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(54) **ONIUM SALT, CHEMICALLY AMPLIFIED
RESIST COMPOSITION AND PATTERN
FORMING PROCESS**

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(57) **ABSTRACT**

An onium salt consisting of a triaryl sulfonium cation containing iodine and fluorine and an aromatic carboxylic acid anion containing at least one iodine atom on the aromatic ring is provided. When processed by photolithography using high-energy radiation, a chemically amplified resist composition comprising the onium salt has advantages including high sensitivity, high resolution, improved lithography properties, and collapse resistance.

ONIUM SALT, CHEMICALLY AMPLIFIED RESIST COMPOSITION AND PATTERN FORMING PROCESS

CROSS-REFERENCE TO RELATED APPLICATIONS

[0001] This non-provisional application claims priority under 35 U.S.C. § 119(a) on Patent Application No. 2024-022670 filed in Japan on Feb. 19, 2024, the entire contents of which are hereby incorporated by reference.

TECHNICAL FIELD

[0002] This invention relates to an onium salt, a chemically amplified resist composition, and a patterning process.

BACKGROUND ART

[0003] To meet the demand for higher integration density and operating speed of LSIs, the effort to reduce the pattern rule is in rapid progress. As the use of 5G high-speed communications and artificial intelligence (AI) is widely spreading, high-performance devices are needed for their processing. As the advanced miniaturization technology, manufacturing of microelectronic devices at the 5-nm node by the lithography using EUV of wavelength 13.5 nm has been implemented in a mass scale. Studies are made on the application of EUV lithography to 3-nm node devices of the next generation and 2-nm node devices of the next-but-one generation.

[0004] As the feature size reduces, image blurs due to acid diffusion become a problem. To insure resolution for fine patterns with a size of 45 nm et seq., not only an improvement in dissolution contrast is important as previously reported, but the control of acid diffusion is also important as reported in Non-Patent Document 1. Since chemically amplified resist compositions are designed such that sensitivity and contrast are enhanced by acid diffusion, an attempt to minimize acid diffusion by reducing the temperature and/or time of post-exposure bake (PEB) fails, resulting in drastic reductions of sensitivity and contrast.

[0005] A triangular tradeoff relationship among sensitivity, resolution, and edge roughness (LWR) has been pointed out. Specifically, a resolution improvement requires to suppress acid diffusion whereas a short acid diffusion distance leads to a decline of sensitivity.

[0006] The addition of an acid generator capable of generating a bulky acid is an effective means for suppressing acid diffusion. It was then proposed to incorporate repeat units derived from an onium salt having a polymerizable unsaturated bond in a polymer. Since this polymer functions as an acid generator, it is referred to as polymer-bound acid generator. Patent Document 1 discloses a sulfonium or iodonium salt having a polymerizable unsaturated bond, capable of generating a specific sulfonic acid. Patent Document 2 discloses a sulfonium salt having a sulfonic acid directly attached to the backbone.

[0007] Resist compositions adapted for the ArF lithography are typically based on (meth)acrylate polymers having acid labile groups. These acid labile groups undergo deprotection reaction when an acid generator capable of generating a sulfonic acid which is substituted at α -position with fluorine (referred to as " α -fluorinated sulfonic acid," hereinafter) is used, but not when an acid generator capable of generating a sulfonic acid which is not substituted at α -po-

sition with fluorine (referred to as " α -non-fluorinated sulfonic acid," hereinafter) or carboxylic acid is used. When a sulfonium or iodonium salt capable of generating α -fluorinated sulfonic acid is mixed with a sulfonium or iodonium salt capable of generating α -non-fluorinated sulfonic acid, the sulfonium or iodonium salt capable of generating α -non-fluorinated sulfonic acid undergoes ion exchange with the α -fluorinated sulfonic acid. Through the ion exchange, the α -fluorinated sulfonic acid once generated upon light exposure is converted back to the sulfonium or iodonium salt. Then the sulfonium or iodonium salt of α -non-fluorinated sulfonic acid or carboxylic acid functions as a quencher. Patent Document 3 discloses a resist composition comprising a sulfonium or iodonium salt capable of generating carboxylic acid as the quencher.

[0008] Sulfonium salt type quenchers capable of generating carboxylic acid are known. Proposed thus far are sulfonium salts of salicylic acid and β -hydroxycarboxylic acid (Patent Document 4), salicylic acid derivatives (Patent Documents 5 and 6), fluorosalicylic acids (Patent Document 7), hydroxynaphthoic acid (Patent Document 8), salicylic acids having an iodized aromatic substituent group introduced therein (Patent Document 9), and salicylic acids having a cyclic acetal structure introduced therein (Patent Document 10). Salicylic acid is quite effective for suppressing acid diffusion due to the intramolecular hydrogen bond of carboxy group and hydroxy group.

[0009] It is pointed out that the agglomeration of a quencher causes to degrade the dimensional uniformity or CDU of resist patterns. It is thus expected that the CDU of resist patterns after development is improved by preventing the quencher from agglomerating in the resist film, for achieving a uniform distribution of the quencher.

[0010] In connection with the demand for further miniaturization, there is a problem that upon development of a positive resist film in an alkaline developer, the resist film is swollen with the developer so that pattern collapse may occur upon small-size pattern formation. To solve the problem associated with miniaturization, the development of an effective material for a new resist composition is important. It is desired to have an onium salt type quencher having a high sensitivity, fully controlled acid diffusion, acceptable solvent solubility, and effective prevention of pattern collapse.

CITATION LIST

- [0011] Patent Document 1: JP-A 2006-045311 (U.S. Pat. No. 7,482,108)
- [0012] Patent Document 2: JP-A 2006-178317
- [0013] Patent Document 3: JP-A 2007-114431
- [0014] Patent Document 4: WO 2018/159560
- [0015] Patent Document 5: JP-A 2020-203984
- [0016] Patent Document 6: JP-A 2020-091404
- [0017] Patent Document 7: JP-A 2020-091312
- [0018] Patent Document 8: JP-A 2019-120760
- [0019] Patent Document 9: JP-A 2022-077505
- [0020] Patent Document 10: WO 2023/189502
- [0021] Non-Patent Document 1: SPIE Vol. 6520 65203L-1 (2007)

SUMMARY OF THE INVENTION

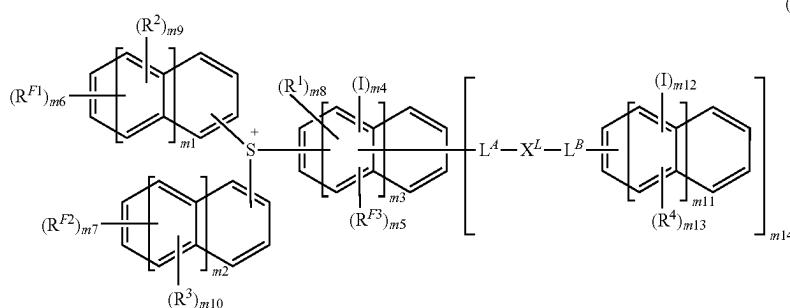
[0022] In conjunction with the demand for higher resolution of resist patterns, a prior art resist composition com-

prising an acid generator of sulfonium salt type and a quencher fails to fully suppress acid diffusion. This raises the problem that lithography properties including contrast, exposure latitude (EL), LWR, CDU, and DOF are degraded. Another problem arising upon formation of small-size patterns is pattern collapse by swell.

[0023] An object of the invention is to provide a novel onium salt and a chemically amplified resist composition comprising the onium salt, the resist composition exhibiting a high sensitivity, high resolution, improved lithography properties including EL, LWR, CDU and DOF, and collapse resistance, when processed by lithography using high-energy radiation such as deep UV, EB, or EUV, independent of whether it is of positive or negative tone. Another object is to provide a pattern forming process using the resist composition.

[0024] The inventor has found that an onium salt consisting of a triaryl sulfonium cation containing iodine and fluorine and an aromatic carboxylic acid anion containing at least one iodine atom on the aromatic ring has solvent solubility, and that a chemically amplified resist composition comprising the onium salt as a quencher exhibits a high sensitivity, high contrast, improved lithography properties including EL, LWR, CDU and DOF, and collapse resistance upon formation of small-size patterns.

[0025] In one aspect, the invention provides an onium salt consisting of a cation having the formula (1A) and an anion having the formula (1B).



[0026] Herein m1 is 0 or 1, m2 is 0 or 1, m3 is 0 or 1, m4 is an integer of 0 to 4, m5 is an integer of 0 to 4, m6 is an integer of 0 to 6, m7 is an integer of 0 to 6, m8 is an integer of 0 to 2, m9 is an integer of 0 to 2, m10 is an integer of 0 to 2, m11 is 0 or 1, m12 is an integer of 0 to 4, m13 is an integer of 0 to 2, m14 is an integer of 0 to 2, meeting $0 \leq m_6 + m_9 \leq 4$ in case of $m_1 = 0$ and $0 \leq m_6 + m_9 \leq 6$ in case of $m_1 = 1$, $0 \leq m_7 + m_{10} \leq 4$ in case of $m_2 = 0$ and $0 \leq m_7 + m_{10} \leq 6$ in case of $m_2 = 1$, $1 \leq m_4 + m_5 + m_8 + m_{14} \leq 4$ in case of $m_3 = 0$ and $1 \leq m_4 + m_5 + m_8 + m_{14} \leq 6$ in case of $m_3 = 1$, $0 \leq m_{12} + m_{13} \leq 4$ in case of $m_{11} = 0$ and $0 \leq m_{12} + m_{13} \leq 6$ in case of $m_{11} = 1$, and $m_4 + m_{12} \geq 1$,

[0027] R^{F1} to R^{F3} are each independently fluorine, a $C_1\text{-}C_6$ fluorinated saturated hydrocarbyl group, $C_1\text{-}C_6$ fluorinated saturated hydrocarboxy group, or $C_1\text{-}C_6$ fluorinated saturated hydrocarbylthio group, a plurality of R^{F1} may be identical or different when m_6 is 2 or more, a plurality of R^{F2} may be identical or different when m_7 is 2 or more, a plurality of R^{F3} may be identical or different when m_5 is 2 or more,

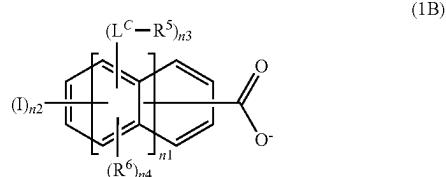
[0028] R^1 to R^4 each are halogen exclusive of iodine and fluorine, nitro group, cyano group, a $C_1\text{-}C_{20}$ hydrocarbyl group which may contain a heteroatom, $C_1\text{-}C_{20}$ hydrocarboxy group which may contain a heteroatom, or $C_1\text{-}C_{20}$ hydrocarbylthio group which may contain a heteroatom, with the proviso that when m_8 is 2, two R^1 may be identical or different and two R^1 may bond together to form a ring with the carbon atoms to which they are attached, when m_9 is 2, two R^2 may be identical or different and two R^2 may bond together to form a ring with the carbon atoms to which they are attached, when m_{10} is 2, two R^3 may be identical or different and two R^3 may bond together to form a ring with the carbon atoms to which they are attached, when m_{13} is 2, two R^4 may be identical or different and two R^4 may bond together to form a ring with the carbon atoms to which they are attached,

[0029] the aromatic rings directly bonded to S^+ in the sulfonium cation may bond together to form a ring with S^+ ,

[0030] L^A and L^B are each independently a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond, and

[0031] X^L is a single bond or a $C_1\text{-}C_{40}$ hydrocarbylene group which may contain a heteroatom.

(1A)



[0032] Herein n_1 is 0 or 1, n_2 is an integer of 1 to 4, n_3 is 1 or 2, n_4 is an integer of 0 to 4, meeting $2 \leq n_2 + n_3 + n_4 \leq 5$ in case of $n_1 = 0$ and $2 \leq n_2 + n_3 + n_4 \leq 7$ in case of $n_1 = 1$,

[0033] L^C is a single bond, oxygen, sulfur, ester bond or carbonate bond,

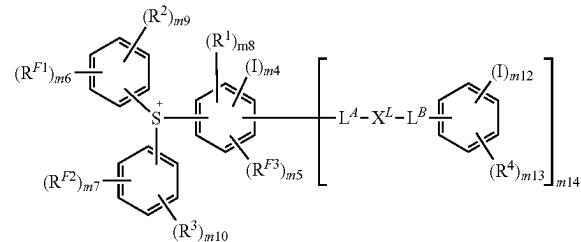
[0034] R^5 is hydrogen or a $C_1\text{-}C_{20}$ hydrocarbyl group which may contain a heteroatom when L^C is a single bond, and hydrogen, a $C_1\text{-}C_{20}$ hydrocarbyl group (exclusive of acid labile group) which may contain a

heteroatom, or acid labile group when L^C is oxygen, sulfur, ester bond or carbonate bond, and

[0035] R^6 is halogen exclusive of iodine, a nitro group, cyano group, C_1 - C_{20} hydrocarbyl group which may contain a heteroatom, C_1 - C_{20} hydrocarboxy group which may contain a heteroatom, or C_1 - C_{20} hydrocarbylthio group which may contain a heteroatom.

[0036] In a preferred embodiment, the cation has the formula (1A-1):

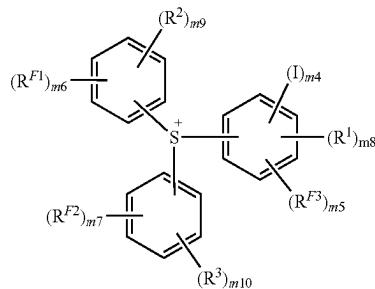
(1A-1)



[0037] wherein m4 to m10, m12 to m14, R^{F1} to R^{F3} , R^1 to R^4 , L^A , L^B and X^L are as defined above.

[0038] More preferably, the cation has the formula (1A-2):

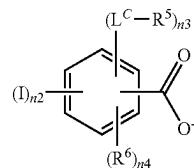
(1A-2)



[0039] wherein m4 to m10, R^{F1} to R^{F3} , and R^1 to R^3 are as defined above.

[0040] In another preferred embodiment, the anion has the formula (1B-1):

(1B-1)



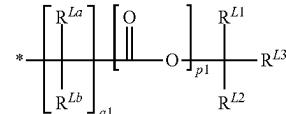
[0041] wherein n2 to n4, L^C , R^5 and R^6 are as defined above.

[0042] Preferably, L^C is oxygen or ester bond.

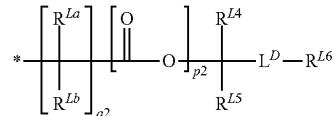
[0043] Also preferably, L^C is oxygen, sulfur, ester bond or carbonate bond and R^5 is an acid labile group.

[0044] Typically, the acid labile group has the formula (AL-1) or (AL-2).

(AL-1)



(AL-2)



[0045] Herein p1 and p2 are each independently 0 or 1, q1 and q2 are each independently an integer of 0 to 4,

[0046] R^{L1} , R^{L2} and R^{L3} are each independently a C_1 - C_{12} hydrocarbyl group in which some $-\text{CH}_2-$ may be replaced by $-\text{O}-$ or $-\text{S}-$, when the hydrocarbyl group contains an aromatic ring, some or all of the hydrogen atoms in the aromatic ring may be substituted by halogen, cyano moiety, nitro moiety, optionally halogenated C_1 - C_4 alkyl moiety, or optionally halogenated C_1 - C_4 alkoxy moiety, R^{L1} and R^{L2} may bond together to form a ring with the carbon atom to which they are attached, some $-\text{CH}_2-$ in the ring may be replaced by $-\text{O}-$ or $-\text{S}-$,

[0047] R^{L4} and R^{L5} are each independently hydrogen or a C_1 - C_{10} hydrocarbyl group, R^{L6} is a C_1 - C_{20} hydrocarbyl group in which some $-\text{CH}_2-$ may be replaced by $-\text{O}-$ or $-\text{S}-$, R^{L5} and R^{L6} may bond together to form a C_3 - C_{20} heterocyclic group with the carbon atom and L^D to which they are attached, some $-\text{CH}_2-$ in the heterocyclic group may be replaced by $-\text{O}-$ or $-\text{S}-$,

[0048] L^D is $-\text{O}-$ or $-\text{S}-$,

[0049] R^{La} to R^{Ld} are each independently hydrogen or a C_1 - C_{20} hydrocarbyl group which may contain a heteroatom, and

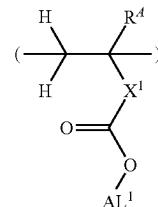
[0050] * designates a point of attachment to the adjacent oxygen or sulfur.

[0051] In another aspect, the invention provides a quencher in the form of the onium salt defined herein.

[0052] In a further aspect, the invention provides a chemically amplified resist composition comprising the quencher defined herein.

[0053] Typically, the resist composition further comprises a base polymer comprising repeat units having the formula (a1).

(a1)



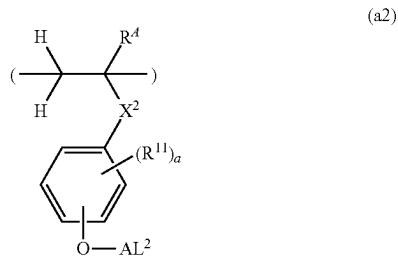
[0054] Herein R^4 is hydrogen, fluorine, methyl or trifluoromethyl,

[0055] X^1 is a single bond, phenylene group, naphthylene group, $^*- \text{C}(=\text{O})-\text{O}-\text{X}^{11} -$ or $^*- \text{C}(=\text{O})-$

NH—X¹¹—, the phenylene or naphthylene group may be substituted with an optionally fluorinated C₁-C₁₀ alkoxy moiety or halogen, X¹¹ is a C₁-C₁₀ saturated hydrocarbylene group which may contain a hydroxy moiety, ether bond, ester bond or lactone ring, or phenylene or naphthylene group, * designates a point of attachment to the carbon atom in the backbone, and

[0056] AL¹ is an acid labile group.

[0057] In a preferred embodiment, the base polymer further comprises repeat units having the formula (a2).



[0058] Herein R⁴ is hydrogen, fluorine, methyl or trifluoromethyl,

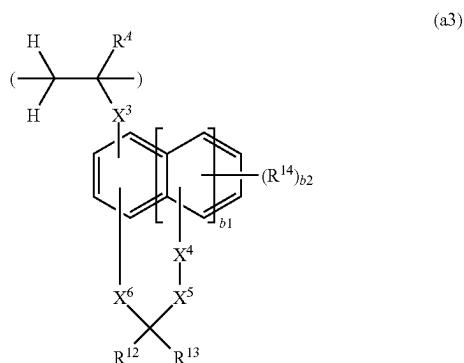
[0059] X² is a single bond or *—C(=O)—O—, * designates a point of attachment to the carbon atom in the backbone,

[0060] R¹¹ is halogen, cyano, a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbyloxy group which may contain a heteroatom, a C₂-C₂₀ hydrocarbylcarbonyl group which may contain a heteroatom, a C₂-C₂₀ hydrocarbylcarbonyloxy group which may contain a heteroatom, or a C₂-C₂₀ hydrocarbyloxcarbonyl group which may contain a heteroatom,

[0061] AL² is an acid labile group, and

[0062] a is an integer of 0 to 4.

[0063] In a preferred embodiment, the base polymer further comprises repeat units having the formula (a3).



[0064] Herein b1 is 0 or 1, b2 is an integer of 0 to 3 in case of b1=0 and an integer of 0 to 5 in case of b1=1,

[0065] R⁴ is hydrogen, fluorine, methyl or trifluoromethyl,

[0066] X³ is a single bond, *—C(=O)—O— or *—C(=O)—NH—, * designates a point of attachment to the carbon atom in the backbone,

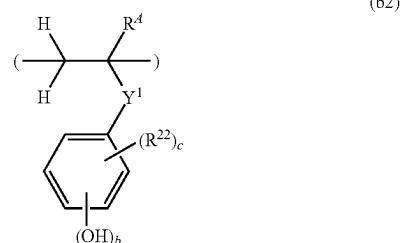
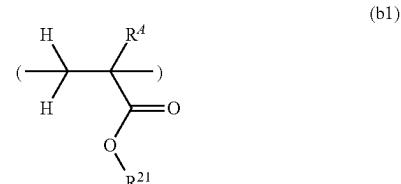
[0067] R¹² and R¹³ are each independently hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, R¹² and R¹³ may bond together to form a ring with the carbon atom to which they are attached,

[0068] R¹⁴ is halogen, hydroxy, cyano, nitro, a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbyloxy group which may contain a heteroatom, a C₂-C₂₀ hydrocarbyloxycarbonyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbylthio group which may contain a heteroatom, or —N(R^{14A})(R^{14B}), R^{14A} and R^{14B} are each independently hydrogen or a C₁-C₆ hydrocarbyl group, a plurality of R¹⁴ may bond together to form a ring with the carbon atoms on the aromatic ring to which they are attached when b2 is 2 or more,

[0069] X⁴ is a single bond, C₁-C₄ aliphatic hydrocarbylene group, carbonyl group, sulfonyl group, or a group obtained by combining the foregoing,

[0070] X⁵ and X⁶ are each independently oxygen or sulfur, X⁴ and X⁶ are bonded to vicinal carbon atoms on the aromatic ring.

[0071] In a preferred embodiment, the base polymer further comprises repeat units having the formula (b1) or (b2).



[0072] Herein R⁴ is each independently hydrogen, fluorine, methyl or trifluoromethyl,

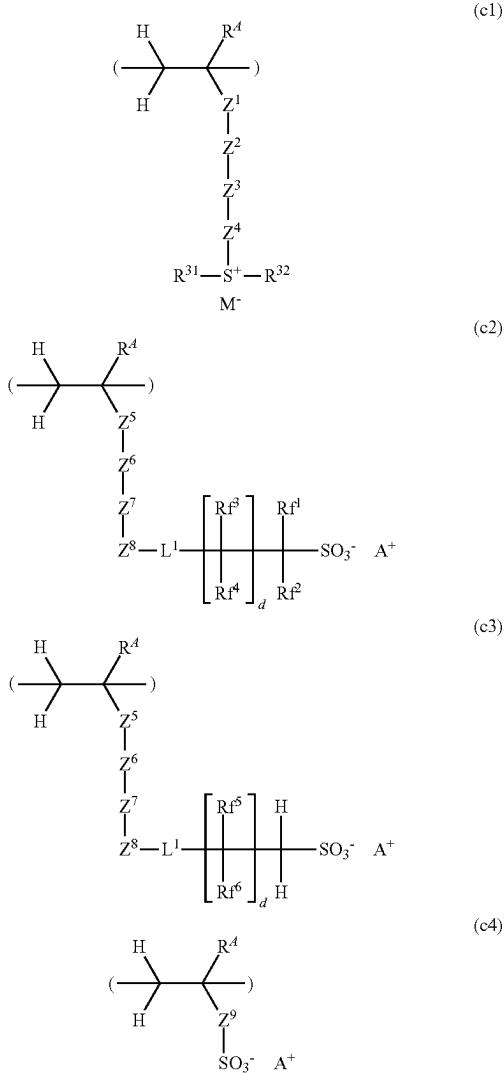
[0073] Y¹ is a single bond or *—C(=O)—O—, * designates a point of attachment to the carbon atom in the backbone,

[0074] R²¹ is hydrogen or a C₁-C₂₀ group containing at least one structure selected from among hydroxy other than phenolic hydroxy, cyano, carbonyl, carboxy, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring and carboxylic anhydride (—C(=O)—O—C(=O)—),

[0075] R²² is halogen, hydroxy, carboxy, nitro, cyano, a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbyloxy group which may contain a heteroatom, a C₂-C₂₀ hydrocarbylcarbonyl group which may contain a heteroatom, a C₂-C₂₀ hydrocarbylcarbonyloxy group which may contain a heteroatom, or a C₂-C₂₀ hydrocarbyloxcarbonyl group which may contain a heteroatom,

[0076] b is an integer of 1 to 4, c is an integer of 0 to 4, and b+c is from 1 to 5.

[0077] In a preferred embodiment, the base polymer further comprises repeat units of at least one type selected from repeat units having the formulae (c1) to (c4).



[0078] Herein R^A is each independently hydrogen, fluorine, methyl or trifluoromethyl,

[0079] Z^1 is a single bond or optionally substituted phenylene group,

[0080] Z^2 is a single bond, $**-C(=O)-O-Z^{21}$, $**-C(=O)-NH-Z^{21}$, or $**-O-Z^{21}$, Z^{21} is a C_1-C_6 aliphatic hydrocarbylene group, phenylene group or a divalent group obtained by combining the foregoing, which may contain halogen, a carbonyl moiety, ester bond, ether bond or hydroxy moiety,

[0081] Z^3 is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond,

[0082] Z^4 is a single bond, or a C_1-C_6 aliphatic hydrocarbylene group, phenylene group or a divalent group

obtained by combining the foregoing, which may contain halogen, carbonyl moiety, ester bond, ether bond or hydroxy moiety,

[0083] Z^5 is each independently a single bond, optionally substituted phenylene group, naphthylene group, or $*-C(=O)-O-Z^{51}$, Z^{51} is a C_1-C_{10} aliphatic hydrocarbylene group which may contain halogen, hydroxy moiety, ether bond, ester bond or lactone ring, or phenylene or naphthylene group,

[0084] Z^6 is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond,

[0085] Z^7 is each independently a single bond, $***-Z^{71}-C(=O)-O-$, $***-C(=O)-NH-Z^{71}-$, or $***-O-Z^{71}-$, Z^{71} is a C_1-C_{20} hydrocarbylene group which may contain a heteroatom,

[0086] Z^8 is each independently a single bond, $****-Z^{81}-C(=O)-O-$, $****-C(=O)-NH-Z^{81}-$, or $****-O-Z^{81}-$, Z^{81} is a C_1-C_{20} hydrocarbylene group which may contain a heteroatom,

[0087] Z^9 is a single bond, methylene, ethylene, phenylene, fluorinated phenylene, trifluoromethyl-substituted phenylene, $*-C(=O)-O-Z^{91}-$, $*-C(=O)-N(H)-Z^{91}-$, or $*-O-Z^{91}-$, Z^{91} is a C_1-C_6 aliphatic hydrocarbylene group, phenylene group, fluorinated phenylene group or trifluoromethyl-substituted phenylene group, which may contain a carbonyl moiety, ester bond, ether bond or hydroxy moiety,

[0088] $*$ designates a point of attachment to the carbon atom in the backbone, $**$ designates a point of attachment to Z^1 , $***$ designates a point of attachment to Z^6 , $****$ designates a point of attachment to Z^7 ,

[0089] R^{31} and R^{32} are each independently a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, R^{31} and R^{32} may bond together to form a ring with the sulfur atom to which they are attached,

[0090] L^1 is a single bond, ether bond, ester bond, carbonyl group, sulfonate ester bond, carbonate bond or carbamate bond,

[0091] Rf^1 and Rf^2 are each independently fluorine or a C_1-C_6 fluorinated saturated hydrocarbyl group,

[0092] Rf^3 and Rf^4 are each independently hydrogen, fluorine, or a C_1-C_6 fluorinated saturated hydrocarbyl group,

[0093] Rf^5 and Rf^6 are each independently hydrogen, fluorine, or a C_1-C_6 fluorinated saturated hydrocarbyl group, excluding that all Rf^5 and Rf^6 are hydrogen at the same time,

[0094] M^- is a non-nucleophilic counter ion,

[0095] A^+ is an onium cation, and

[0096] d is 0, 1, 2 or 3.

[0097] The resist composition may further comprise an organic solvent, a photoacid generator capable of generating a strong acid, a quencher other than the quencher defined herein, and/or a surfactant.

[0098] In a further aspect, the invention provides a pattern forming process comprising the steps of applying the chemically amplified resist composition defined herein onto a substrate to form a resist film thereon, exposing the resist film to high-energy radiation, and developing the exposed resist film in a developer.

[0099] Typically, the high-energy radiation is KrF excimer laser radiation, ArF excimer laser radiation, EB or EUV of wavelength 3 to 15 nm.

Advantageous Effects of Invention

[0100] When processed by lithography, a chemically amplified resist composition comprising the inventive onium salt as a quencher exhibits a high sensitivity, high contrast, improved lithography properties including EL, LWR, CDU and DOF.

DETAILED DESCRIPTION OF THE INVENTION

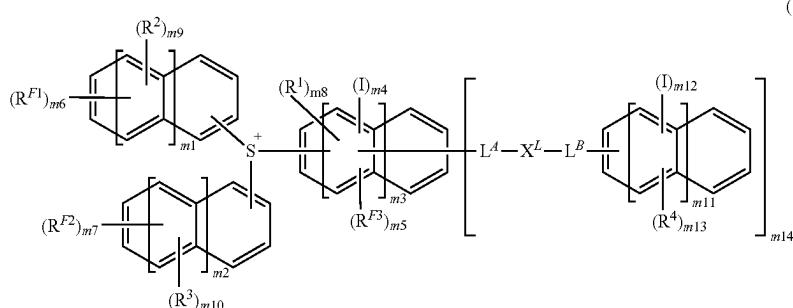
[0101] As used herein, the singular forms "a," "an" and "the" include plural referents unless the context clearly dictates otherwise. "Optional" or "optionally" means that the subsequently described event or circumstances may or may not occur, and that description includes instances where the event or circumstance occurs and instances where it does not. The notation (C_n-C_m) means a group containing from n to m carbon atoms per group. In chemical formulae, the broken line (—) and asterisk (*) designate a point of attachment or valence bond. Me stands for methyl and Ac for acetyl. As used herein, the term "fluorinated" refers to a fluorine-substituted or fluorine-containing compound or group, and "iodized" refers to an iodine-substituted or iodine-containing compound or group. The terms "group" and "moiety" are interchangeable.

[0102] The abbreviations and acronyms have the following meaning.

- [0103] EB: electron beam
- [0104] EUV: extreme ultraviolet
- [0105] Mw: weight average molecular weight
- [0106] Mn: number average molecular weight
- [0107] Mw/Mn: molecular weight distribution or dispersity
- [0108] GPC: gel permeation chromatography
- [0109] PEB: post-exposure bake
- [0110] PAG: photoacid generator
- [0111] LWR: line width roughness
- [0112] CDU: critical dimension uniformity
- [0113] EL: exposure latitude
- [0114] DOF: depth of focus

[Onium Salt]

[0115] One embodiment of the invention is an onium salt which contains a cation having the formula (1A).



[0116] In formula (1A), m1 is 0 or 1. The relevant structure is a benzene ring in case of m1=0, and a naphthalene ring in case of m1=1. From the aspect of solvent solubility, the benzene ring corresponding to m1=0 is preferred. The

subscript m2 is 0 or 1. The relevant structure is a benzene ring in case of m2=0, and a naphthalene ring in case of m2=1. From the aspect of solvent solubility, the benzene ring corresponding to m2=0 is preferred. The subscript m3 is 0 or 1. The relevant structure is a benzene ring in case of m3=0, and a naphthalene ring in case of m3=1. From the aspect of solvent solubility, the benzene ring corresponding to m3=0 is preferred.

[0117] In formula (1A), m4 is an integer of 1 to 4. Since a cation structure containing more iodine atoms is more absorptive to EUV, but loses solvent solubility so that it may precipitate in a resist composition, it is preferred that m4 be 0, 1, 2 or 3, more preferably 0, 1 or 2.

[0118] In formula (1A), m5 is an integer of 0 to 4. It is preferred from the aspect of reactant availability that m5 be 0, 1, 2 or 3, more preferably 0, 1 or 2. The subscript m6 is an integer of 0 to 6. It is preferred from the aspect of reactant availability that m6 be 0, 1, 2 or 3, more preferably 0, 1 or 2. The subscript m7 is an integer of 0 to 6. It is preferred from the aspect of reactant availability that m7 be 0, 1, 2 or 3, more preferably 0, 1 or 2.

[0119] In formula (1A), m8 is an integer of 0 to 2. It is preferred from the aspect of reactant availability that m8 be 0 or 1. The subscript m9 is an integer of 0 to 2. It is preferred from the aspect of reactant availability that m9 be 0 or 1. The subscript m10 is an integer of 0 to 2. It is preferred from the aspect of reactant availability that m10 be 0 or 1.

[0120] In formula (1A), m11 is 0 or 1. The relevant structure is a benzene ring in case of m11=0 and a naphthalene ring in case of m11=1. From the aspect of solvent solubility, the benzene ring corresponding to m11=0 is preferred.

[0121] In formula (1A), m12 is an integer of 0 to 4. Since a cation structure containing more iodine atoms is more absorptive to EUV, but loses solvent solubility so that it may precipitate in a resist composition, it is preferred that m12 be 0, 1, 2 or 3, more preferably 0, 1 or 2.

[0122] In formula (1A), m13 is an integer of 0 to 2. It is preferred from the aspect of reactant availability that m13 be 0 or 1. The subscript m14 is an integer of 0 to 2. It is preferred from the aspect of synthesis that m14 be 0 or 1.

[0123] It is noted that m6+m9 is from 0 to 4 when m1=0, m6+m9 is from 0 to 6 when m1=1; m7+m10 is from 0 to 4 when m2=0, m7+m10 is from 0 to 6 when m2=1; m4+m5+

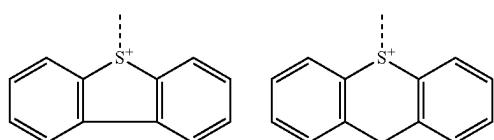
m8+m14 is from 1 to 4 when m3=0, m4+m5+m8+m14 is from 1 to 6 when m3=1; m12+m13 is from 0 to 4 when m11=0, m12+m13 is from 0 to 6 when m11=1; and m4+m12 is 1 or greater.

[0124] In formula (1A), R^{F1} to R^{F3} are each independently fluorine, a C₁-C₆ fluorinated saturated hydrocarbyl group, C₁-C₆ fluorinated saturated hydrocarbyloxy group, or C₁-C₆ fluorinated saturated hydrocarbylthio group. Of these, trifluoromethyl, trifluoromethoxy, and trifluorothiomethoxy are preferred. A plurality of R^{F1} may be identical or different when m6 is 2 or more, a plurality of R^{F2} may be identical or different when m7 is 2 or more, and a plurality of R^{F3} may be identical or different when m5 is 2 or more.

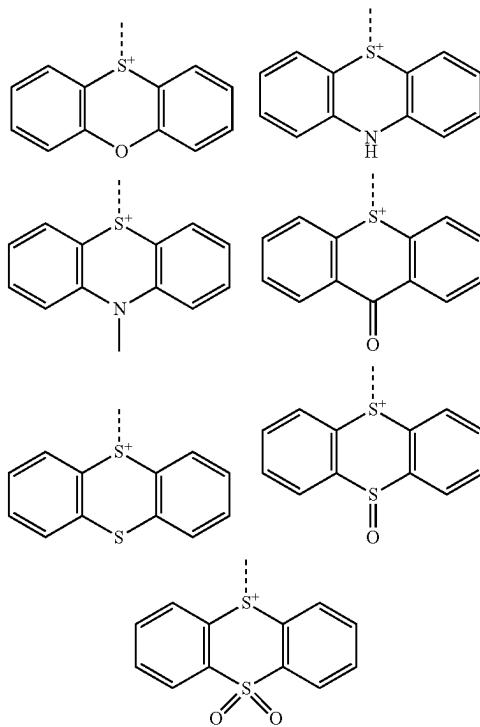
[0125] In formula (1A), R¹ to R⁴ are each independently halogen exclusive of iodine and fluorine, nitro, cyano, a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, C₁-C₂₀ hydrocarbyloxy group which may contain a heteroatom, or C₁-C₂₀ hydrocarbylthio group which may contain a heteroatom. The hydrocarbyl group and hydrocarbyl moiety in the hydrocarbyloxy and hydrocarbylthio groups may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for the hydrocarbyl group R¹. In the hydrocarbyl group and hydrocarbyl moiety in the hydrocarbyloxy and hydrocarbylthio groups, some or all of the hydrogen atoms may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some constituent —CH₂— may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy moiety, cyano moiety, fluorine, chlorine, bromine, iodine, carbonyl moiety, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (—C(=O)—O—C(=O)—) or haloalkyl moiety.

[0126] When m8=2, two R¹ may be identical or different and two R¹ may bond together to form a ring with the carbon atoms to which they are attached. When m9=2, two R² may be identical or different and two R² may bond together to form a ring with the carbon atoms to which they are attached. When m10=2, two R³ may be identical or different and two R³ may bond together to form a ring with the carbon atoms to which they are attached. When m13=2, two R⁴ may be identical or different and two R⁴ may bond together to form a ring with the carbon atoms to which they are attached. Examples of the ring thus formed include cyclopropane, cyclobutane, cyclopentane, cyclohexane, norbornane, and adamantan rings. In the ring, some or all of the hydrogen atoms may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some constituent —CH₂— may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the ring may contain a hydroxy moiety, fluorine, chlorine, bromine, iodine, cyano moiety, carbonyl moiety, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (—C(=O)—O—C(=O)—) or haloalkyl moiety.

[0127] The aromatic rings directly bonded to S⁺ in the sulfonium cation having formula (1A) may bond together to form a ring with S⁺. Exemplary structures of the ring are shown below.



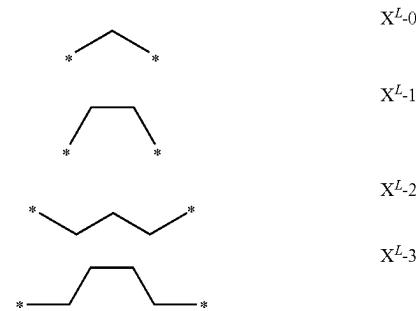
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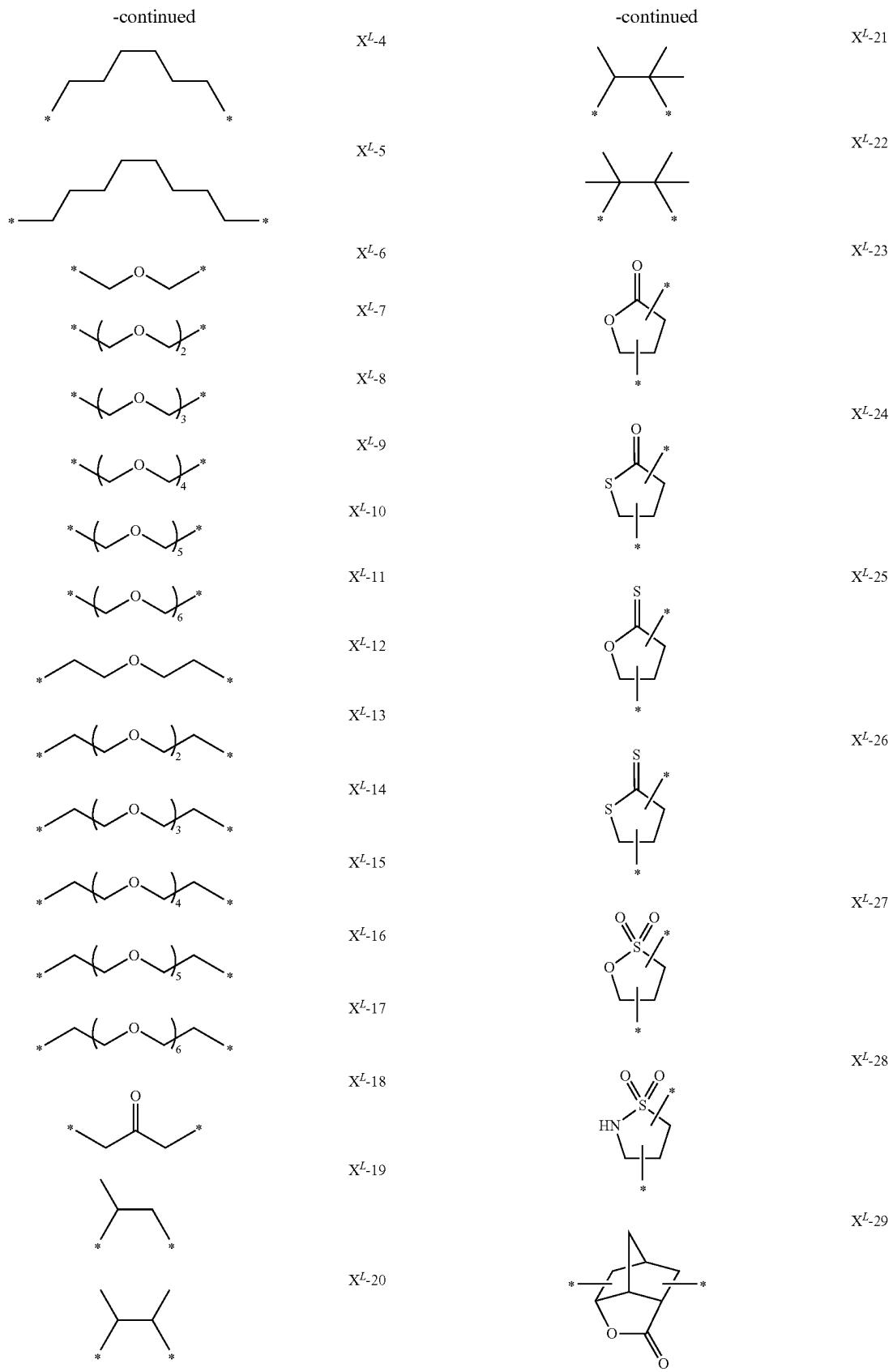


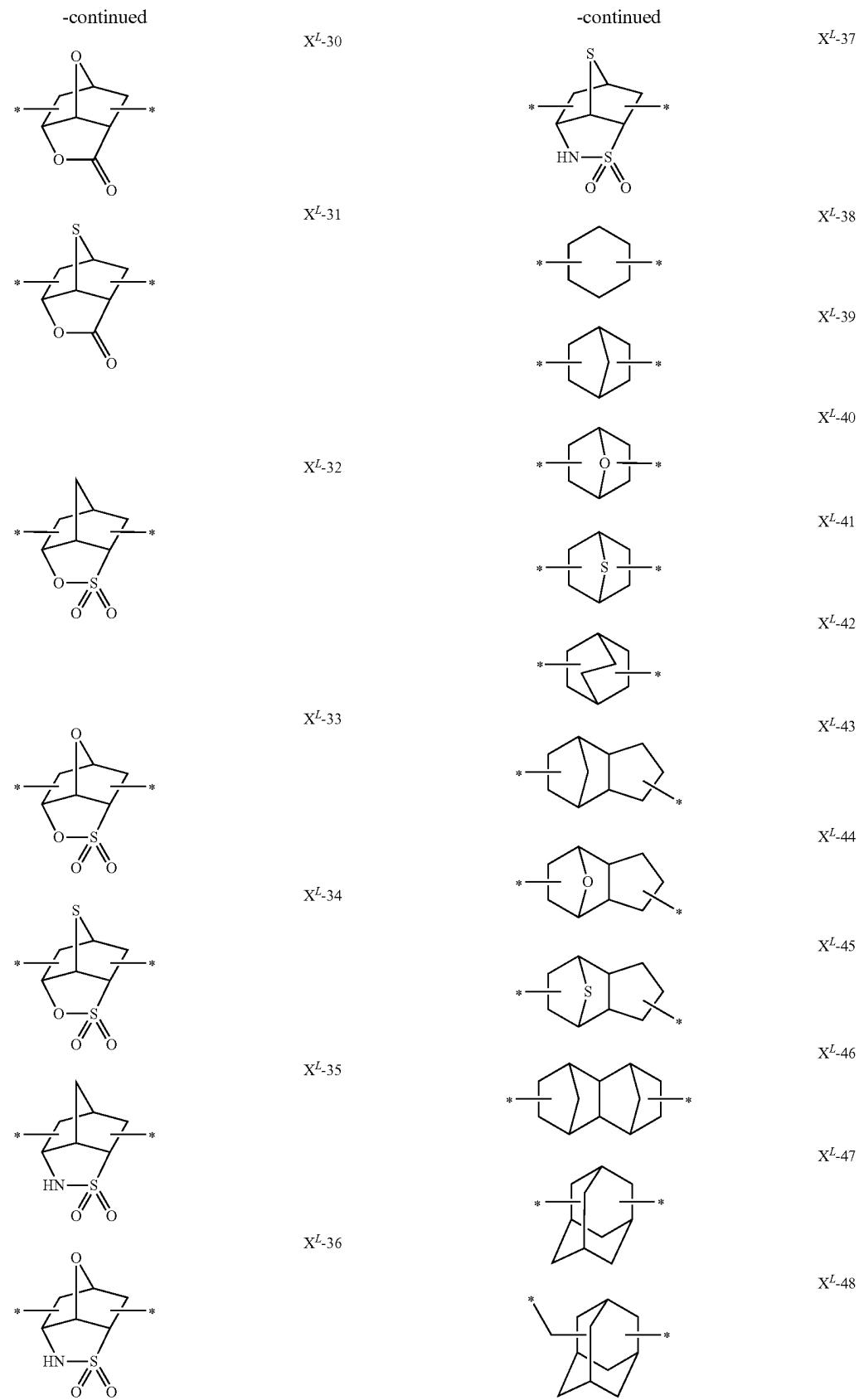
[0128] In formula (1A), L^A and L^B are each independently a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond. L^A is preferably a single bond, ether bond, ester bond or sulfonate ester bond, more preferably an ester bond or sulfonate ester bond. L^B is preferably a single bond, ether bond or ester bond, more preferably a single bond.

[0129] In formula (1A), X^L is a single bond or a C₁-C₄₀ hydrocarbylene group which may contain a heteroatom. The C₁-C₄₀ hydrocarbylene group may be straight, branched or cyclic. Suitable hydrocarbylene groups include alkanediyl, cyclic saturated hydrocarbylene and arylene groups. Suitable heteroatoms include oxygen, nitrogen and sulfur atoms.

[0130] Examples of the optionally heteroatom-containing C₁-C₄₀ hydrocarbylene group X^L are shown below, but not limited thereto. Herein * each designates a point of attachment to

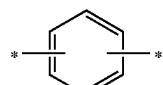
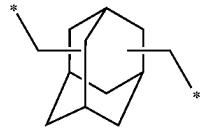




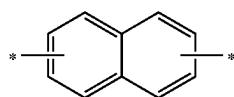


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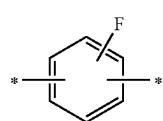
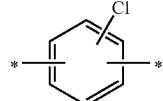
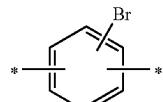
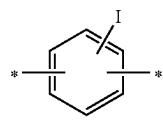
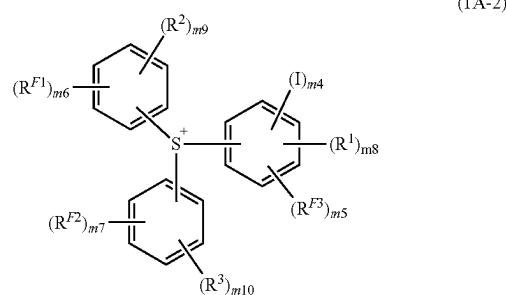
[0132] Preferably the sulfonium cation having formula (1A) has the formula (1A-1):

 X^L-50

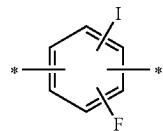
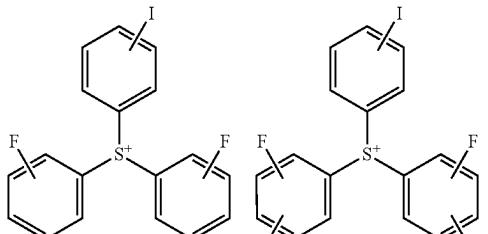
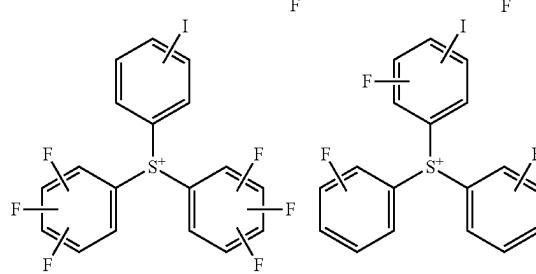
(1A-1)

 X^L-51

[0133] wherein m4 to m10, m12 to m14, R^{F1} to R^{F3} , R^1 to R^4 , L^A , L^B and X^L are as defined above.

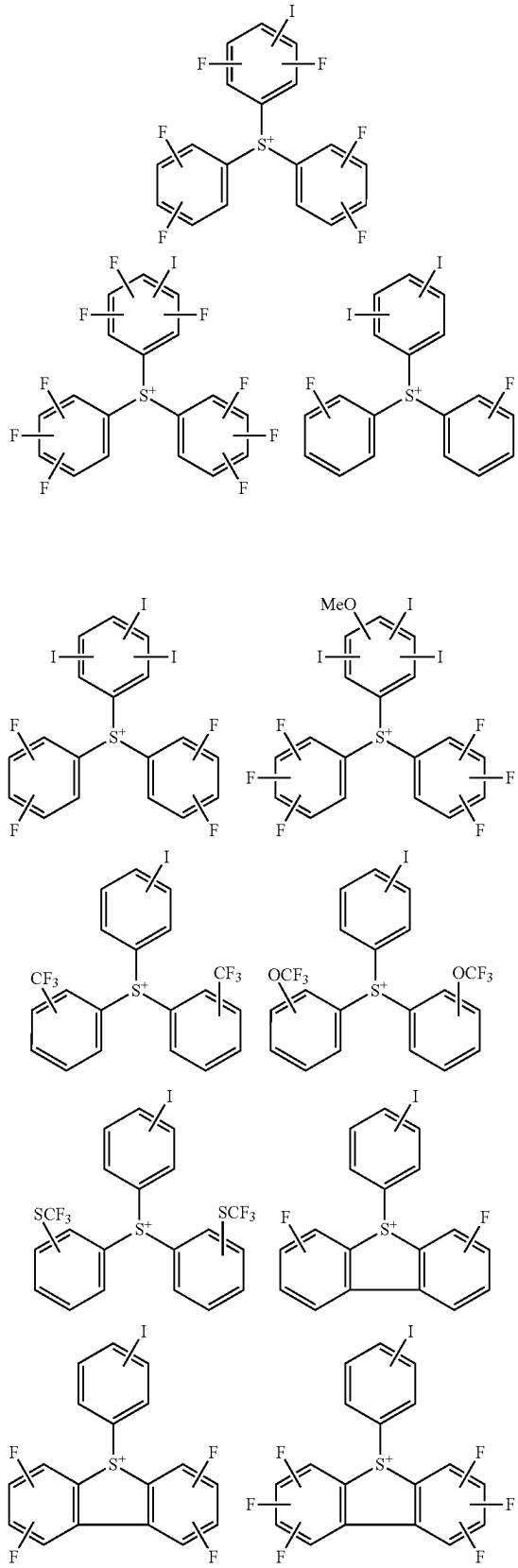
 X^L-52  X^L-53  X^L-54  X^L-55  X^L-56

[0135] wherein m4 to m10, R^{F1} to R^{F3} , and R^1 to R^3 are as defined above.

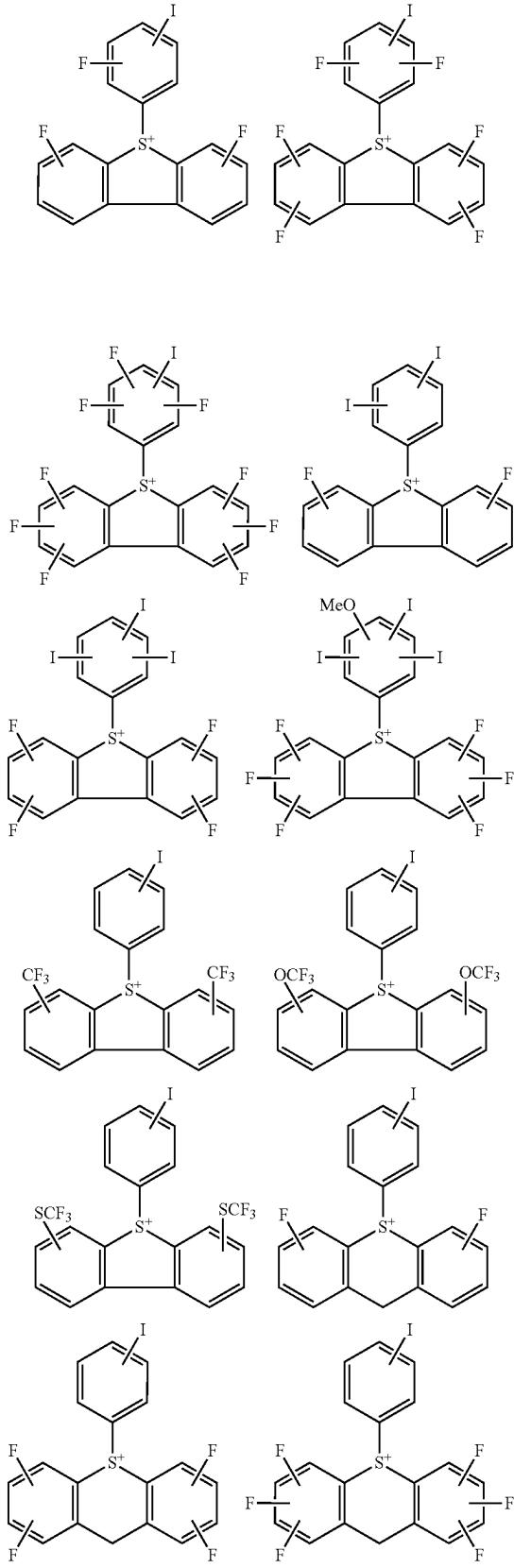
 X^L-57  X^L-58 

[0131] Of these, X^L-0 to X^L-22 , X^L-29 to X^L-34 , and X^L-47 to X^L-58 are preferred.

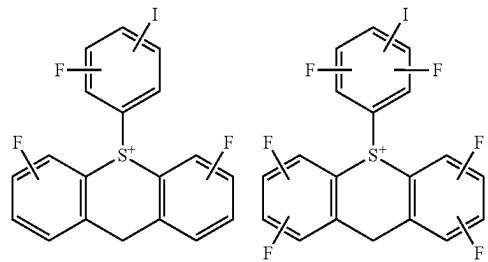
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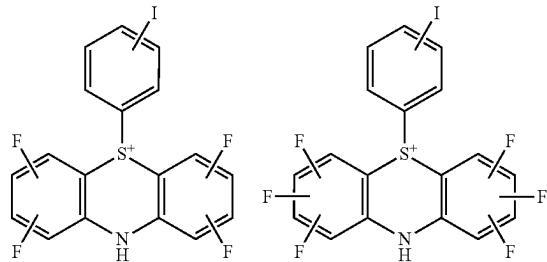
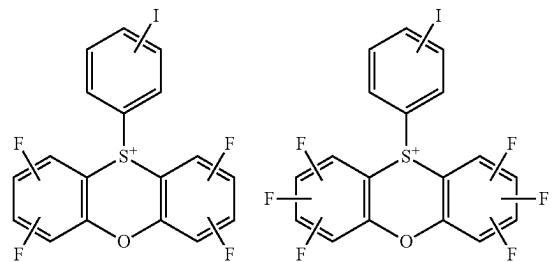
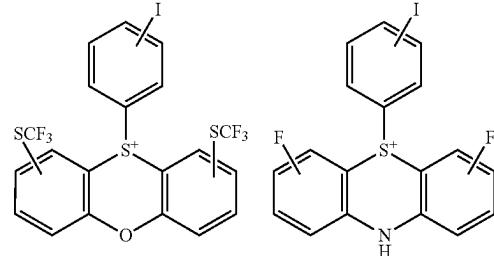
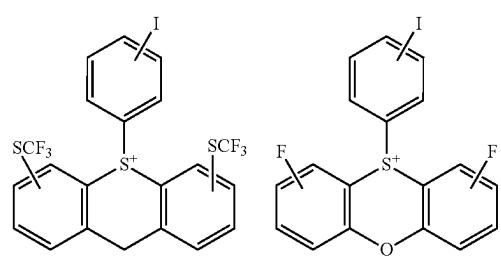
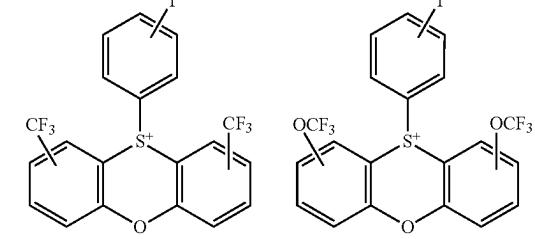
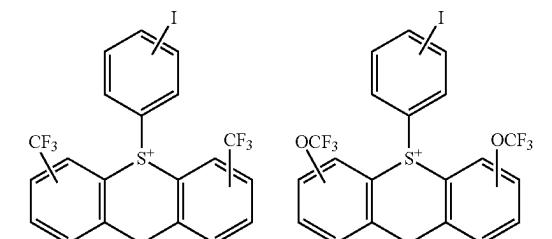
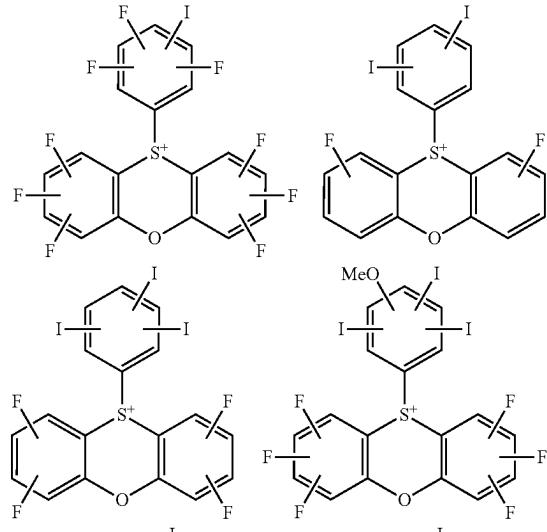
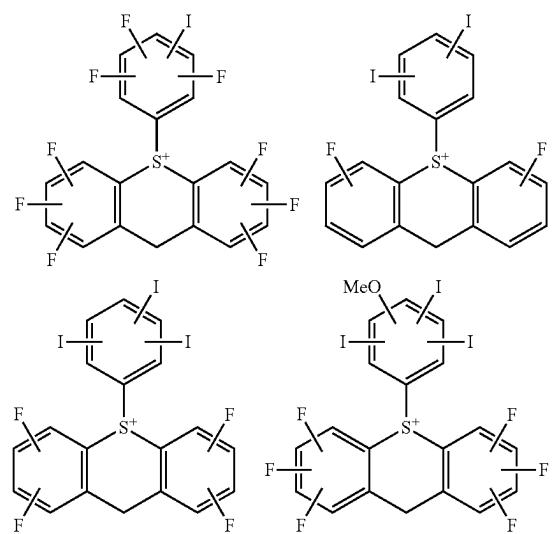
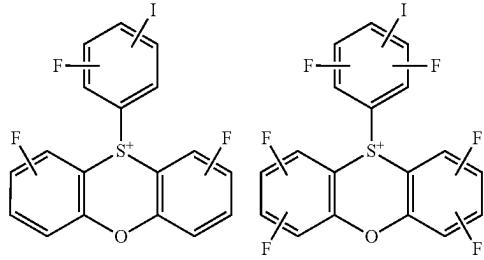
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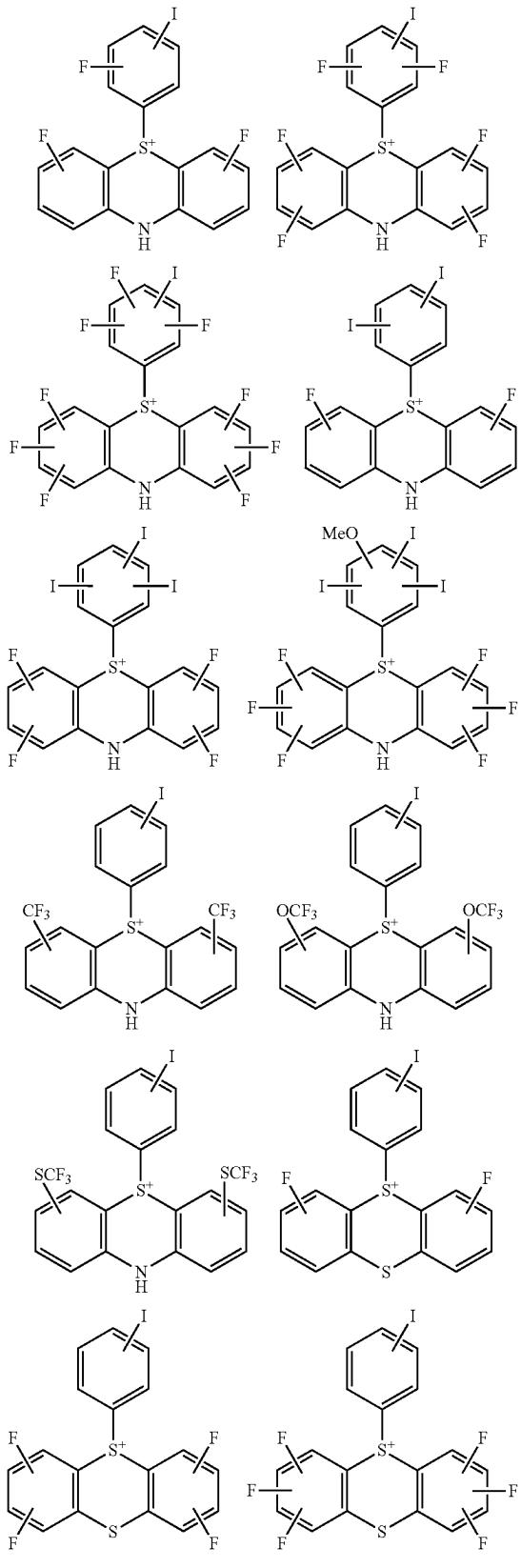
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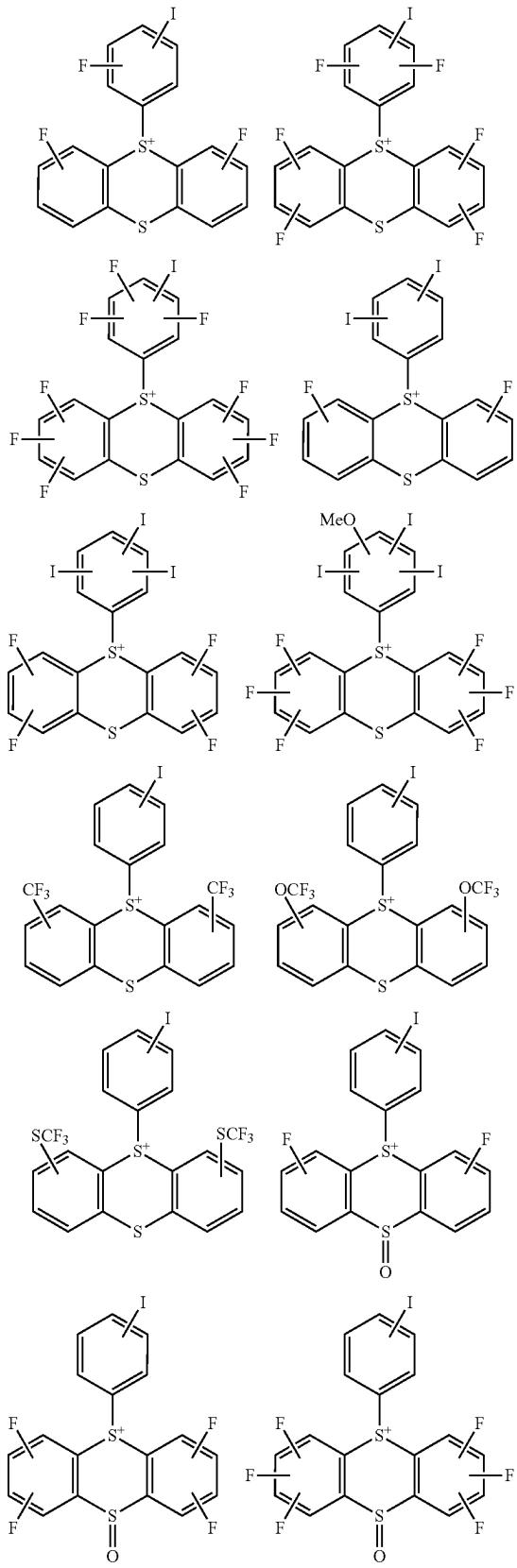
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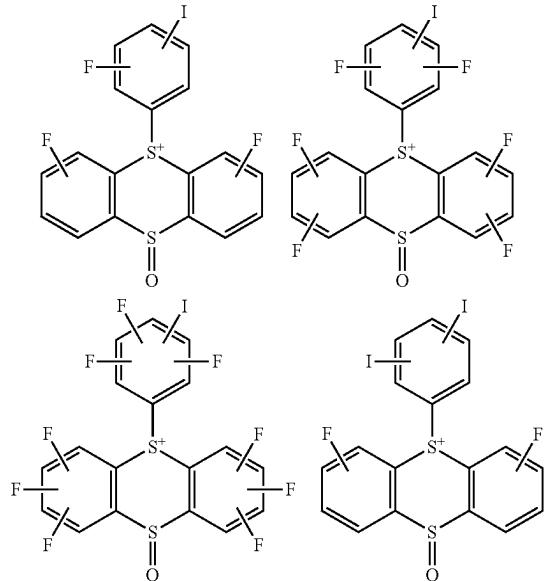
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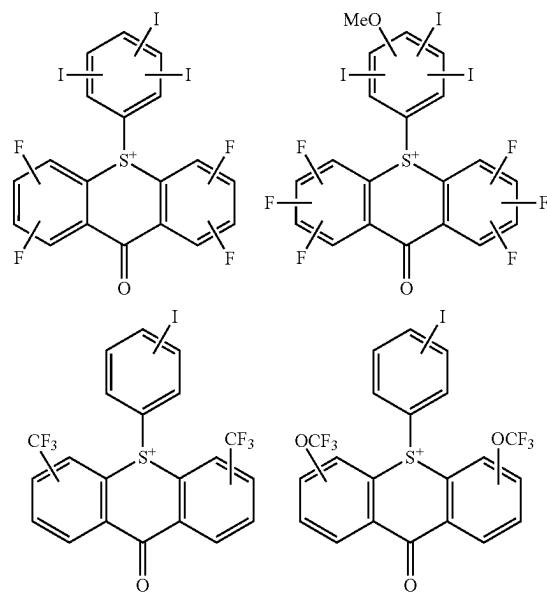
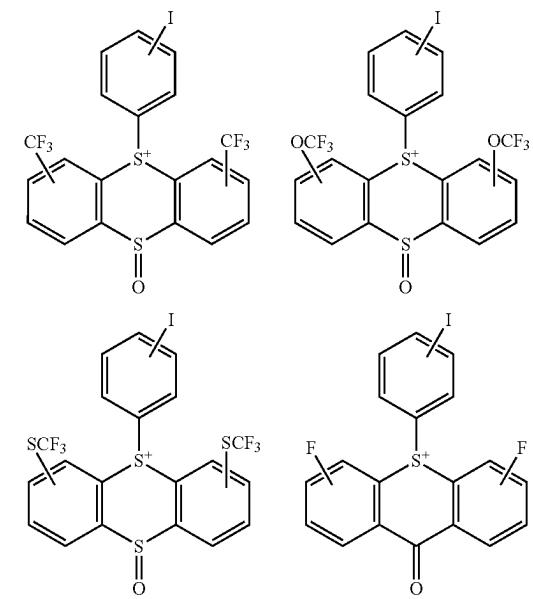
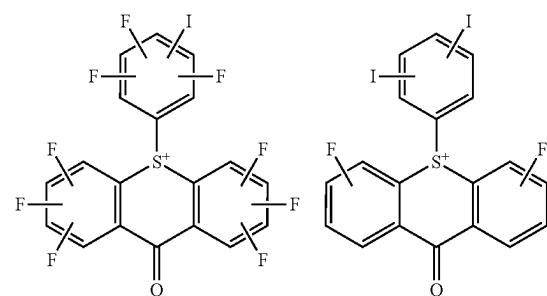
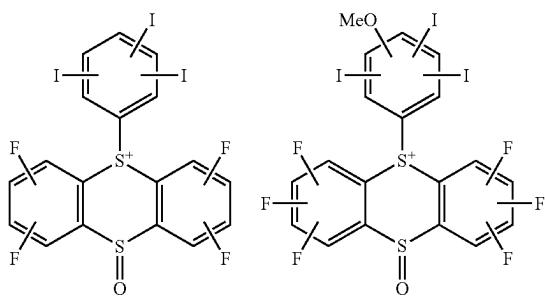
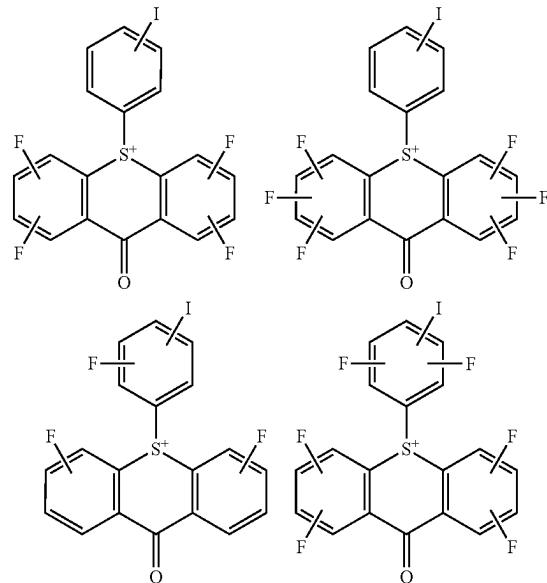
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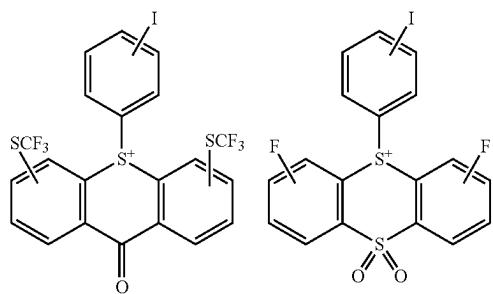
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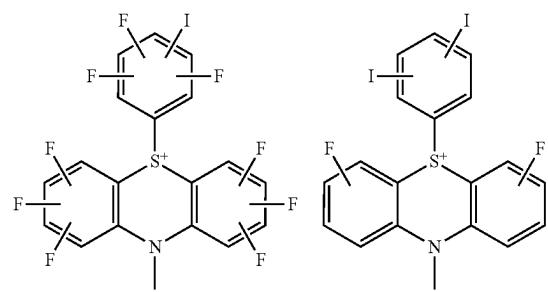
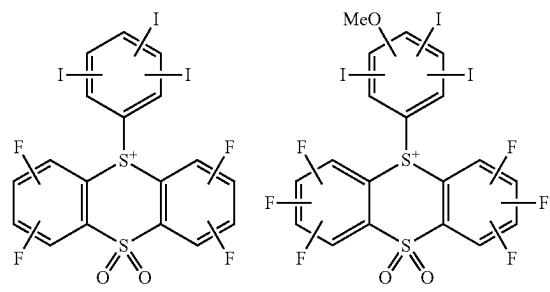
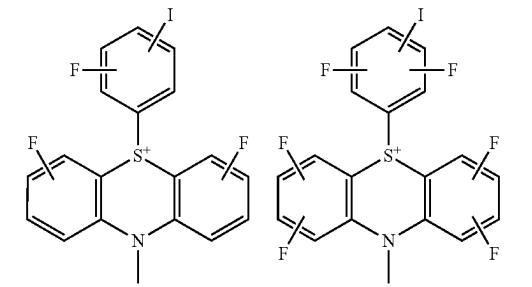
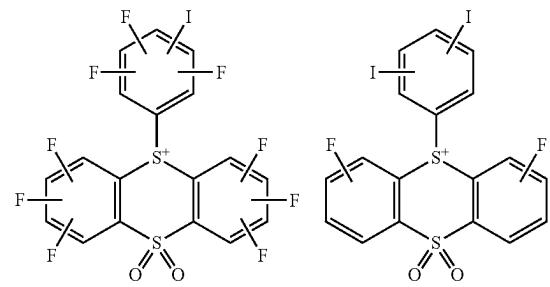
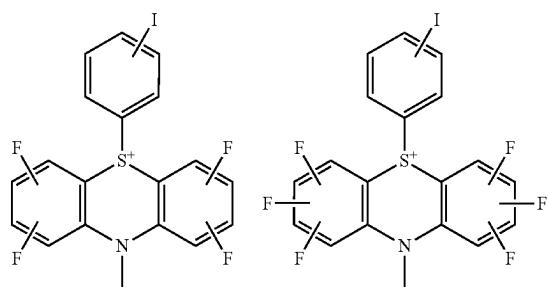
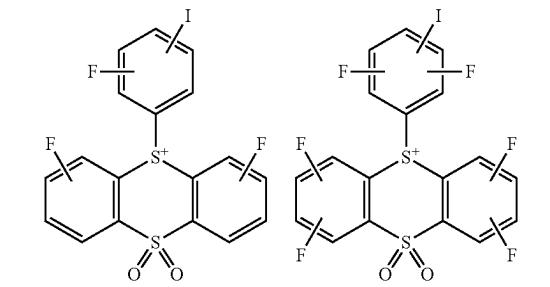
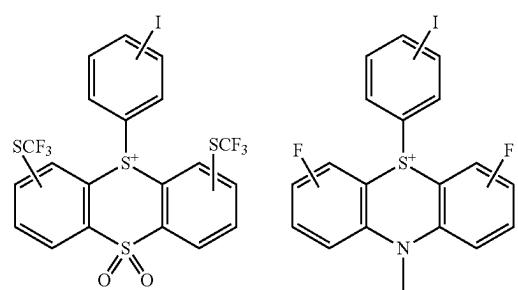
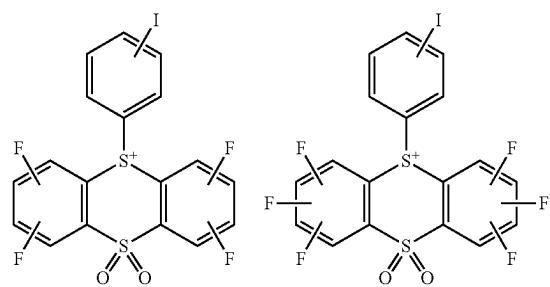
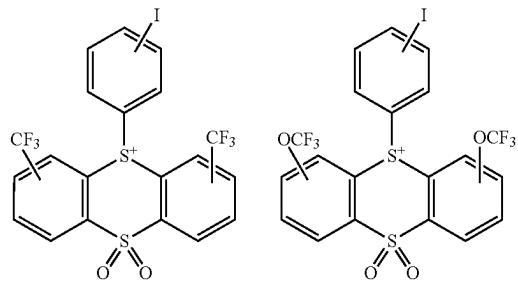
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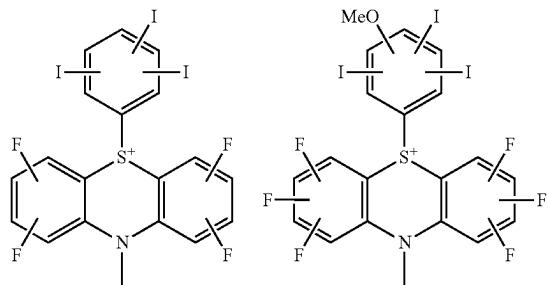
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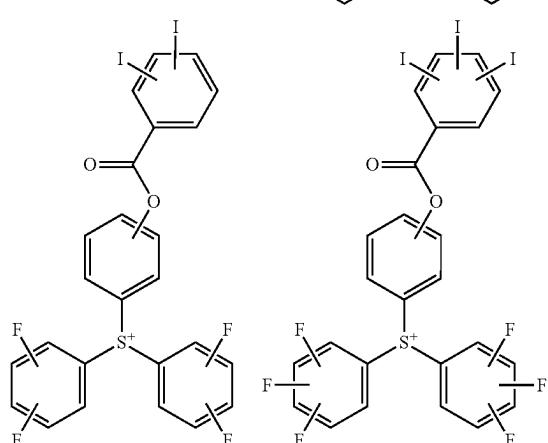
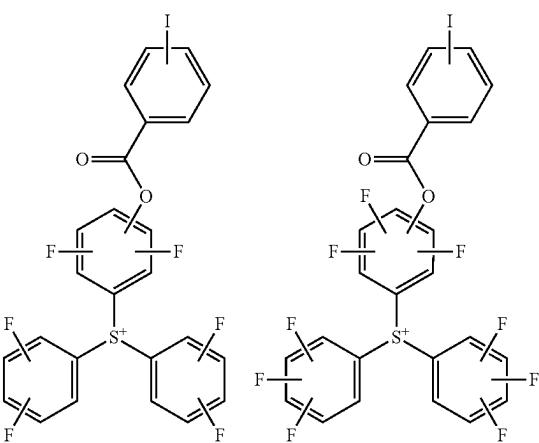
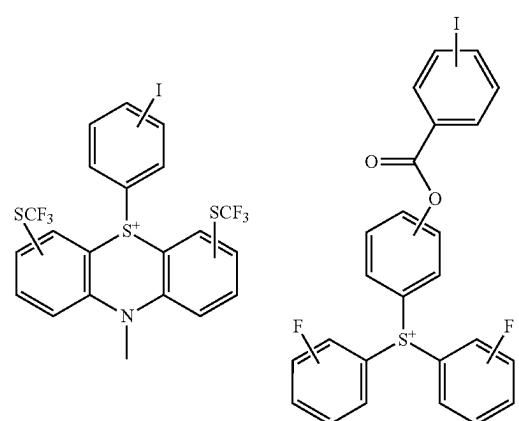
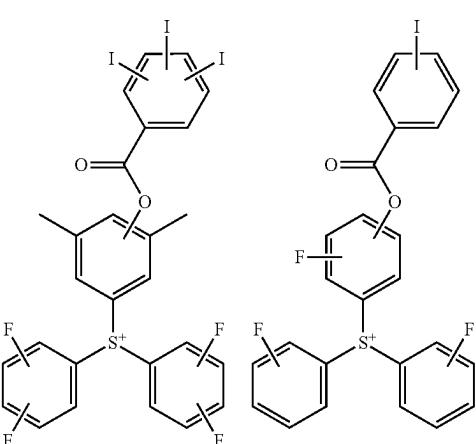
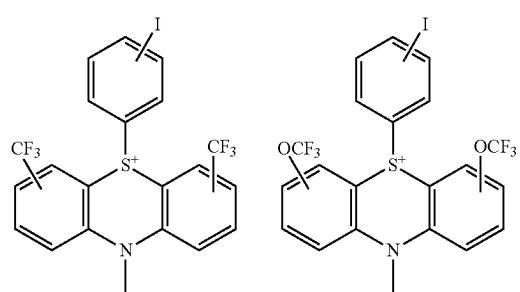
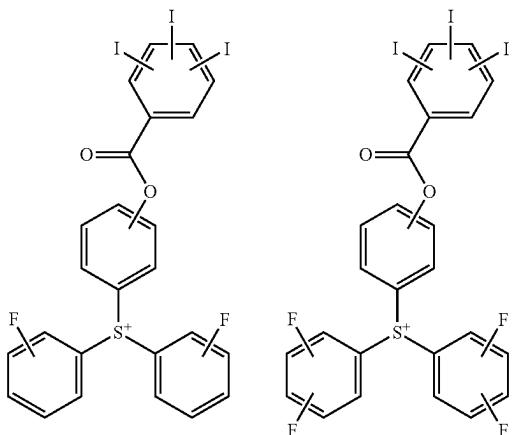
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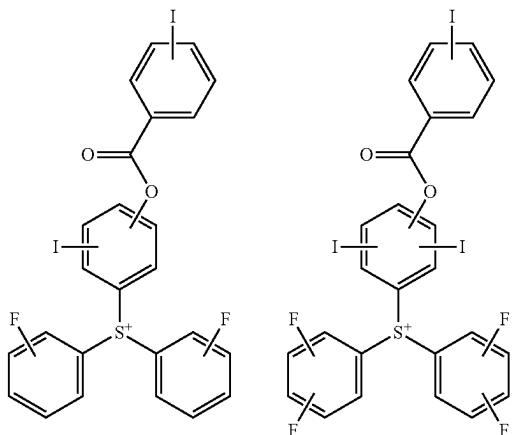
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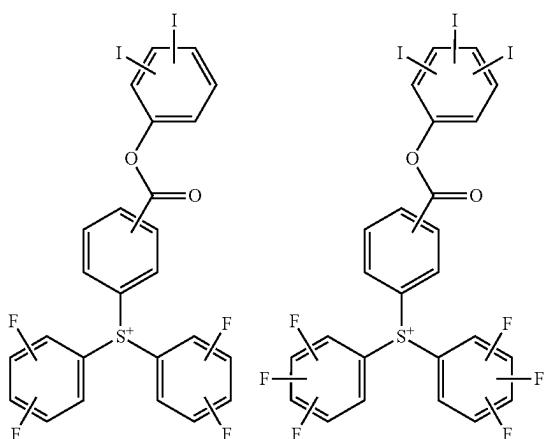
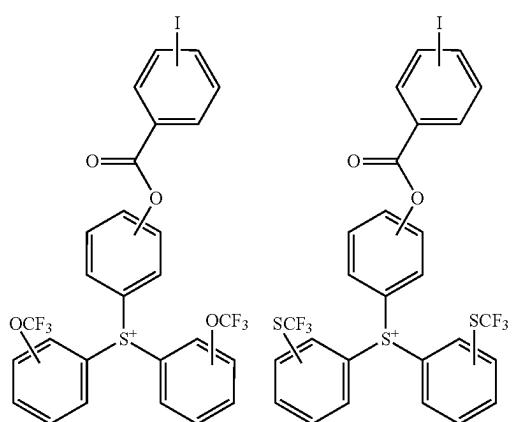
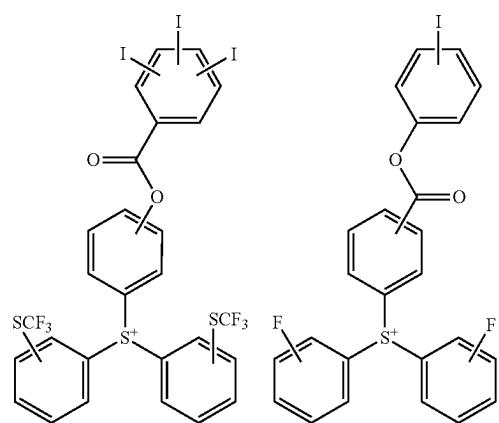
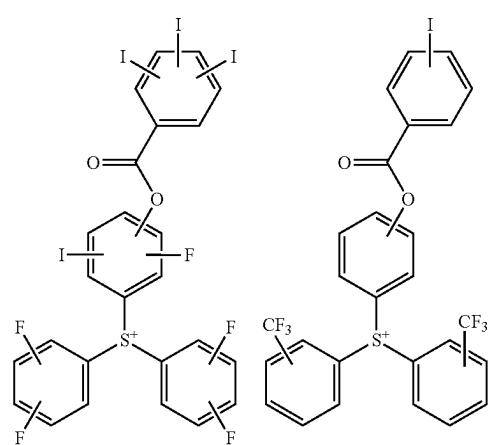
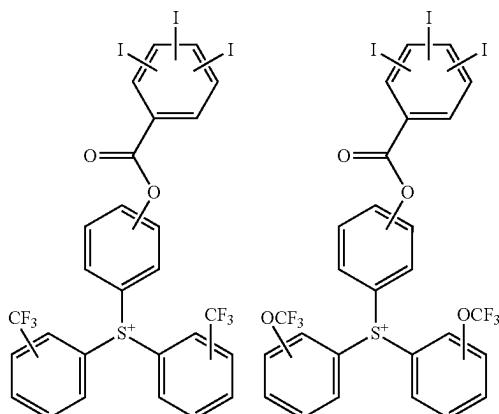
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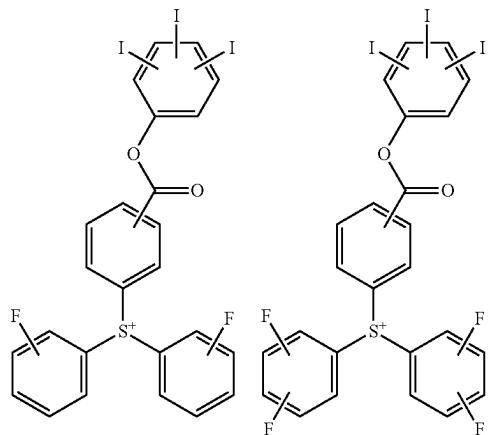
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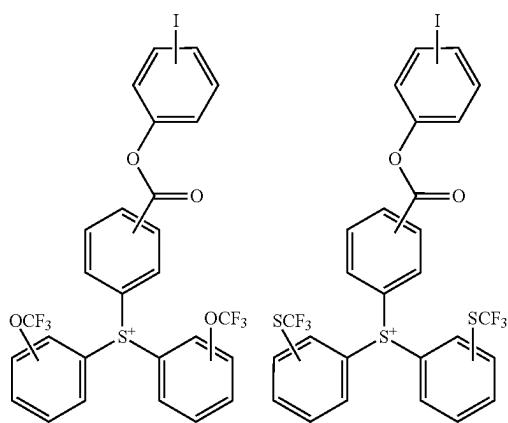
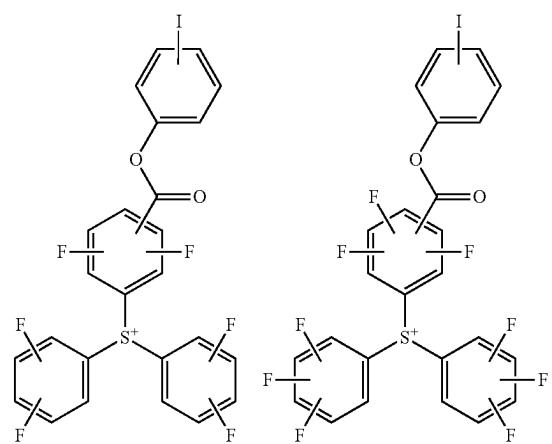
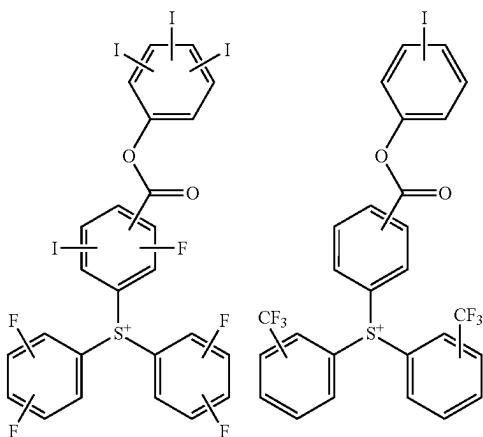
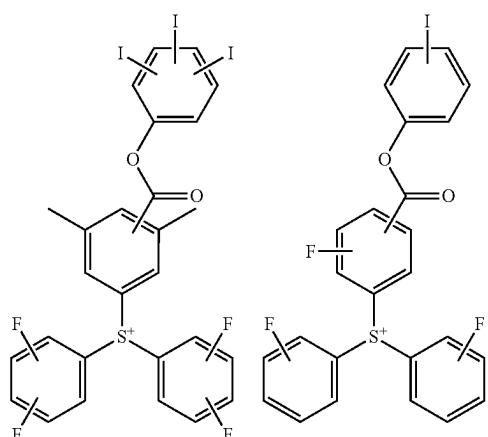
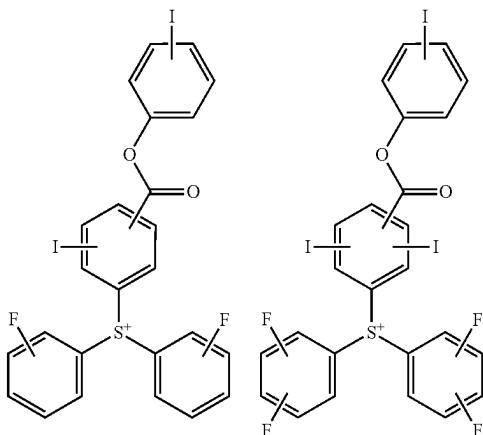
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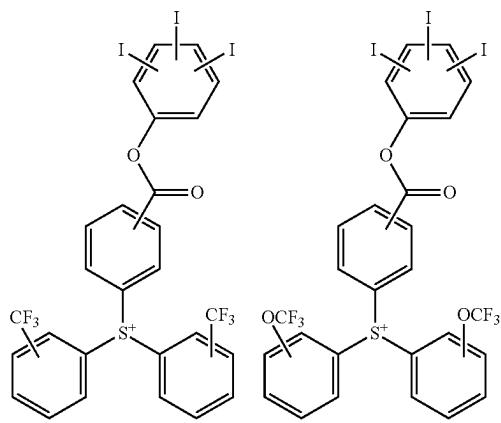
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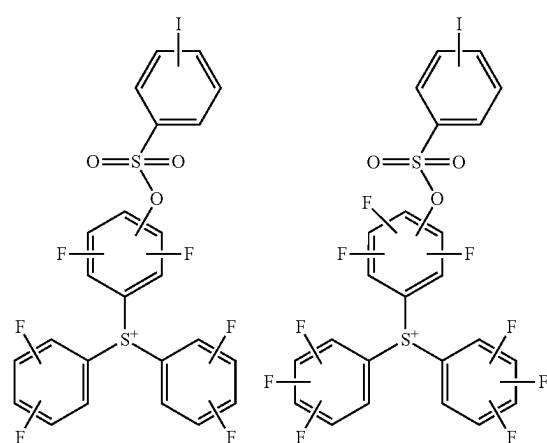
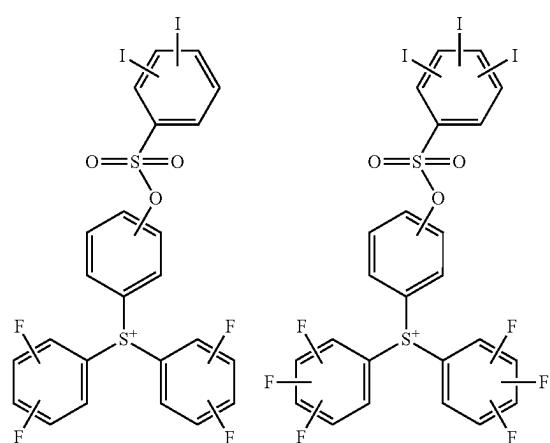
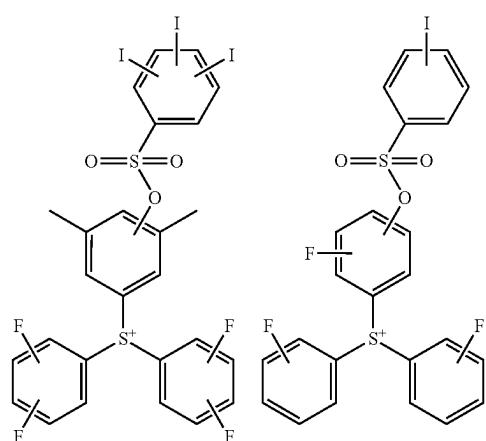
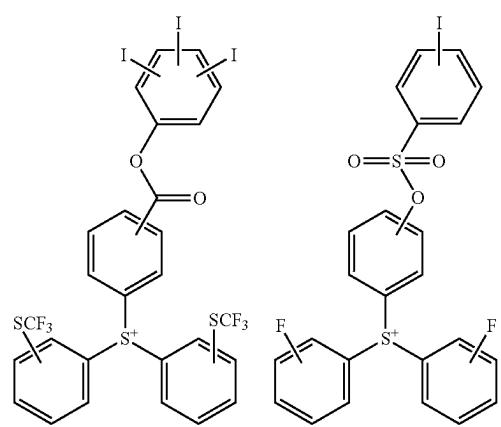
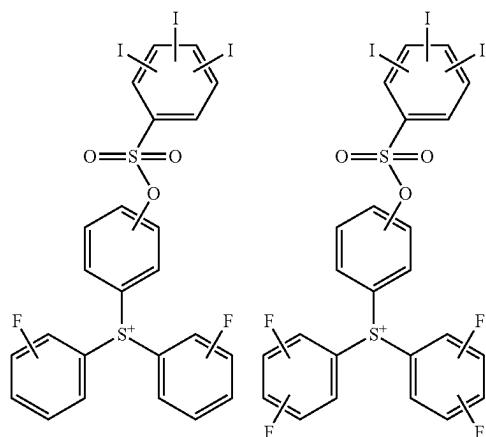
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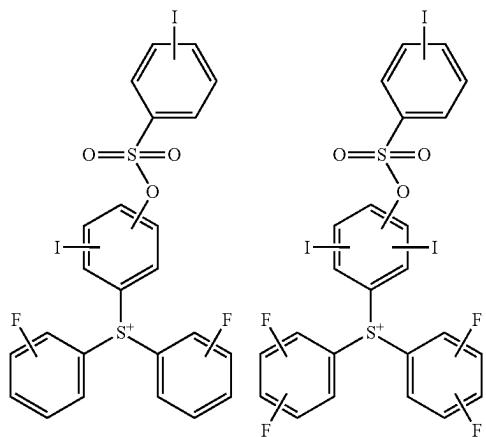
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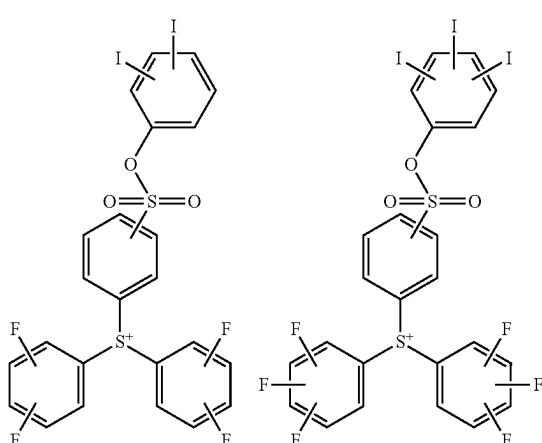
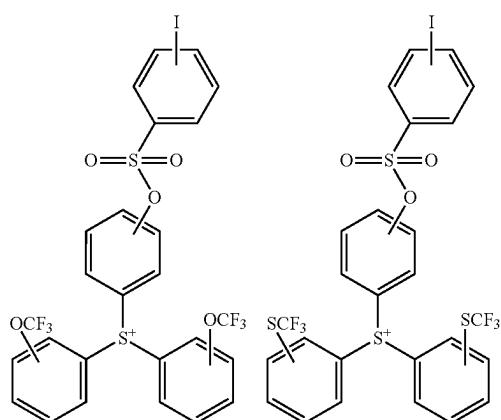
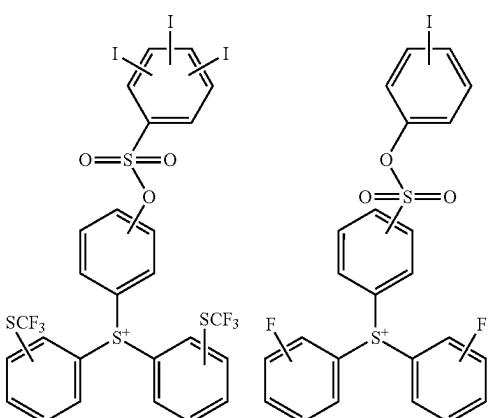
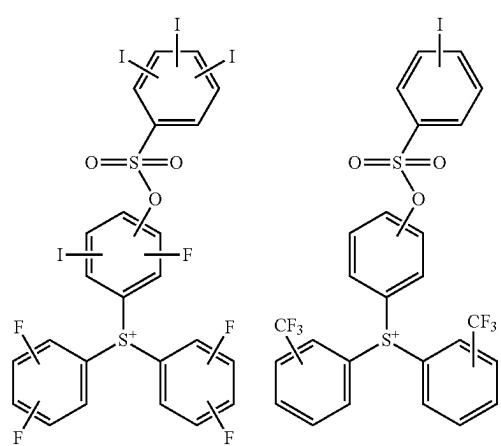
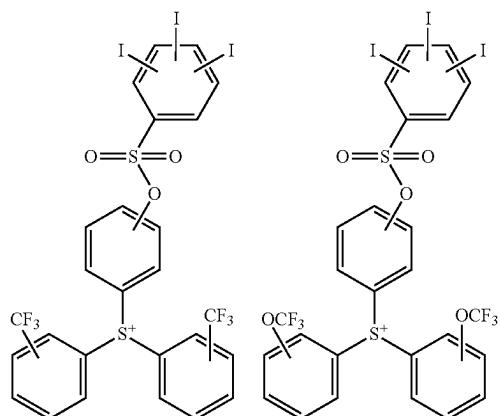
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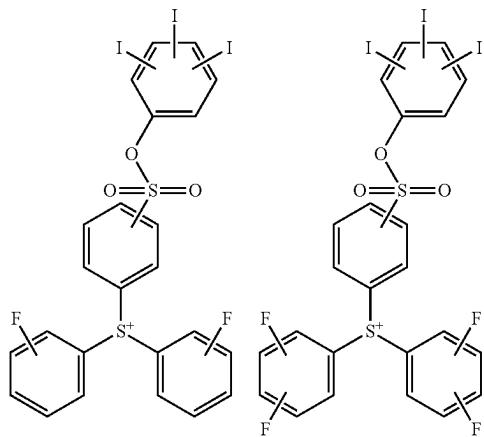
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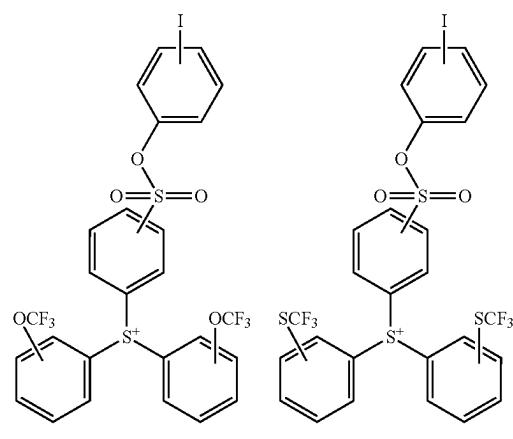
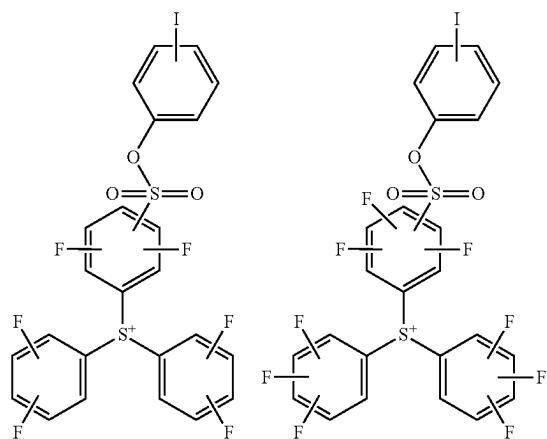
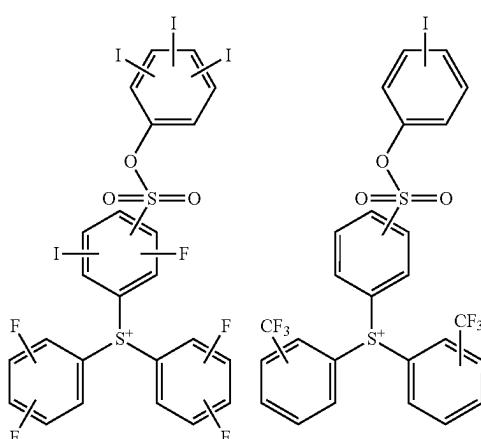
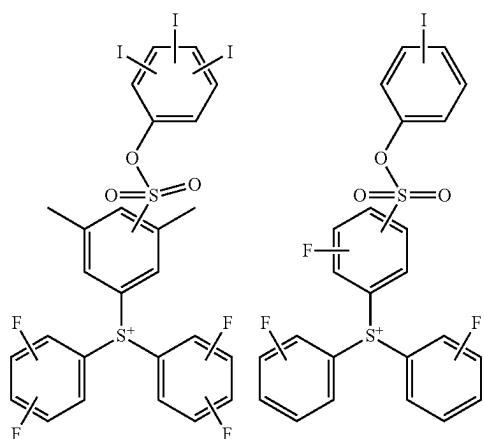
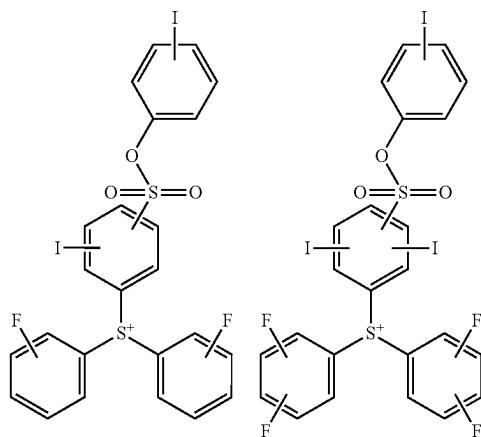
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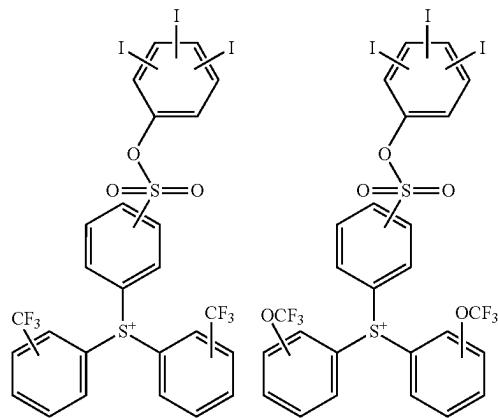
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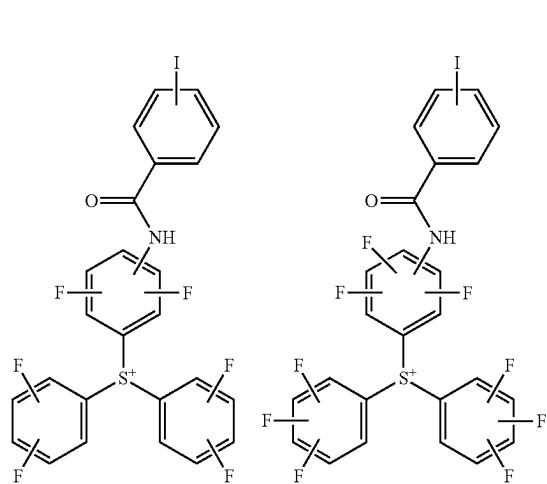
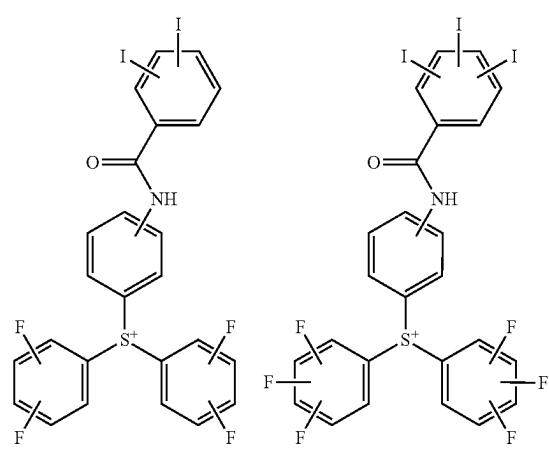
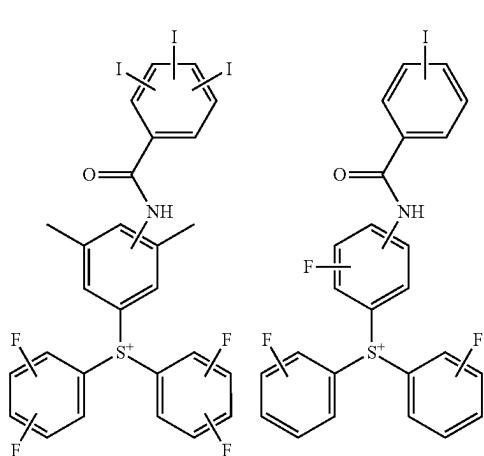
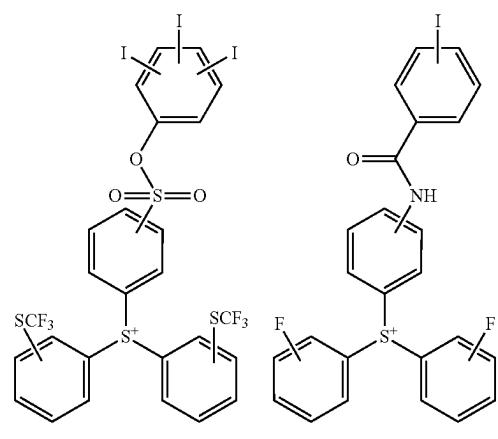
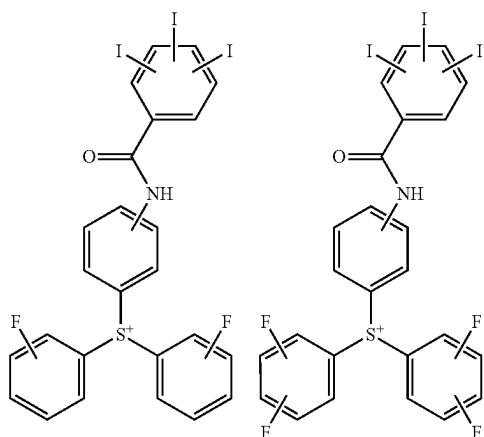
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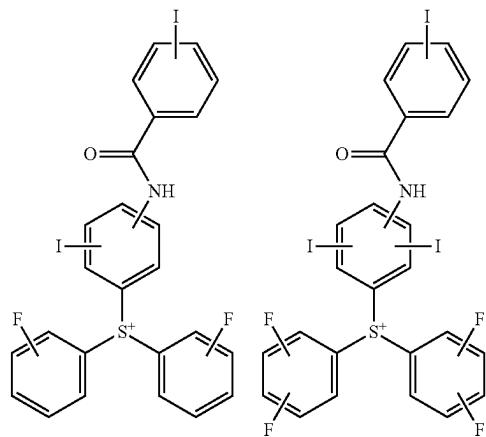
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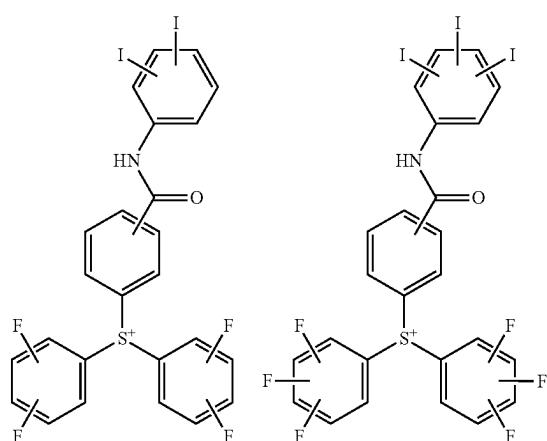
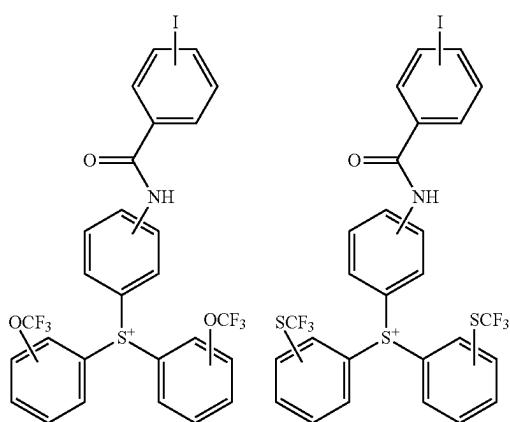
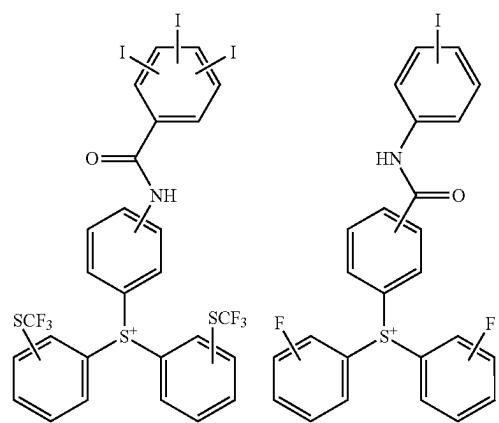
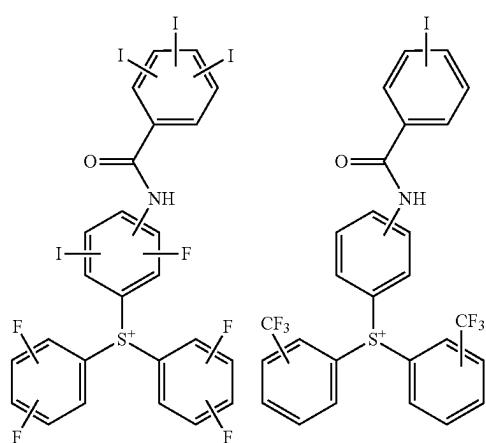
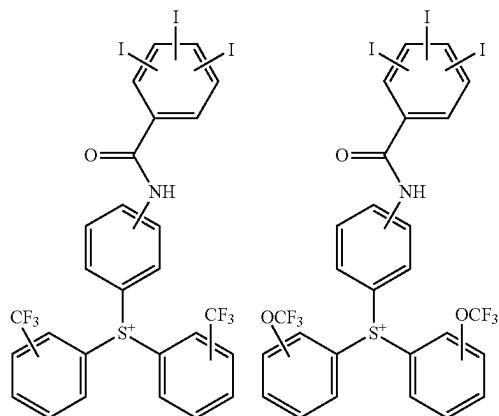
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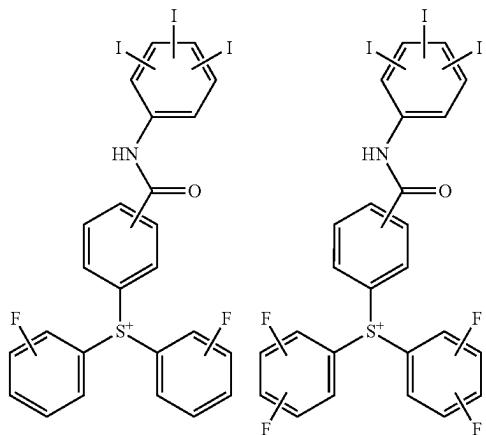
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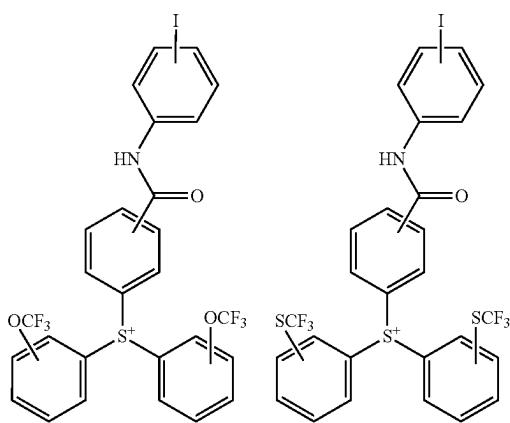
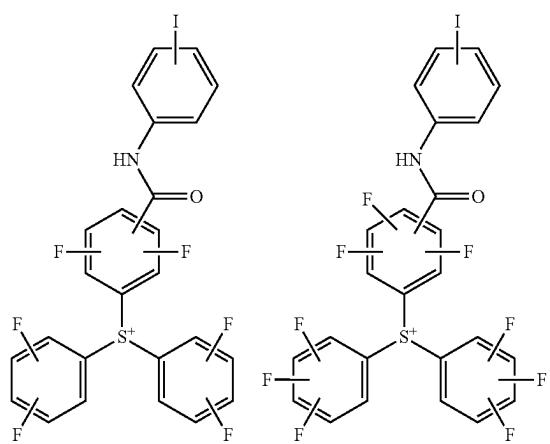
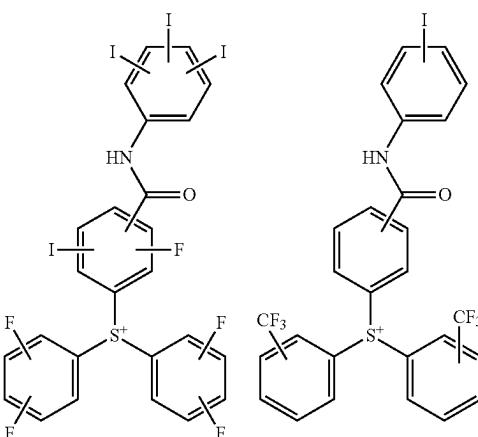
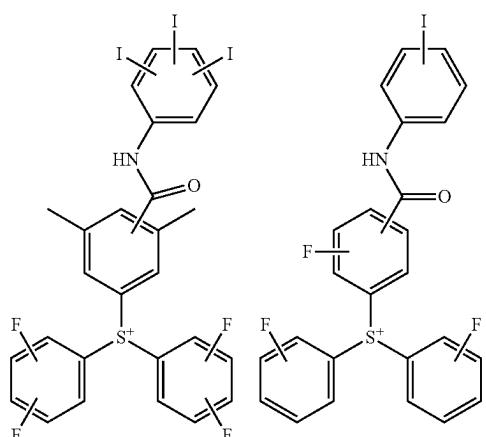
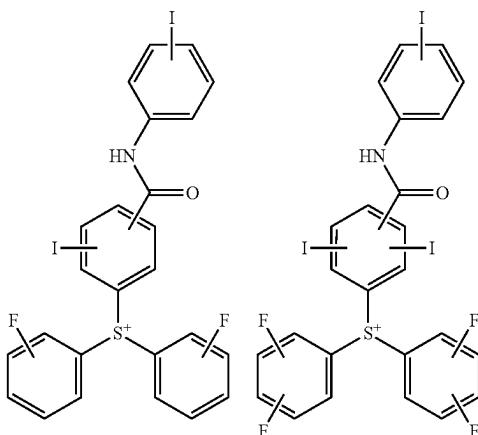
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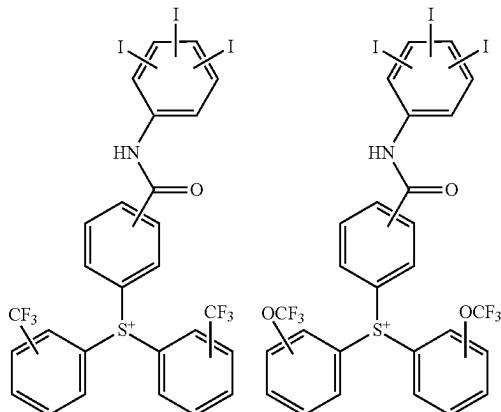
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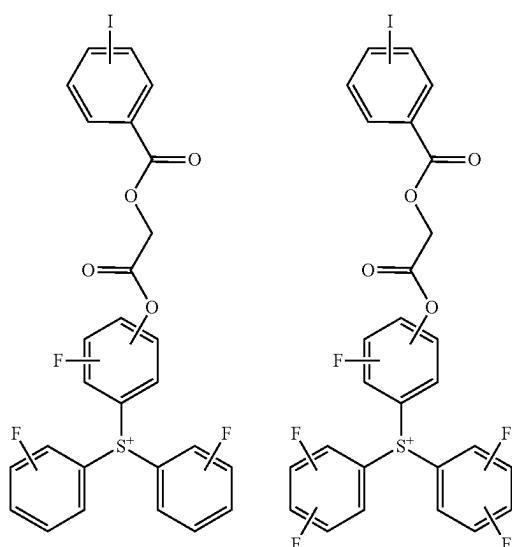
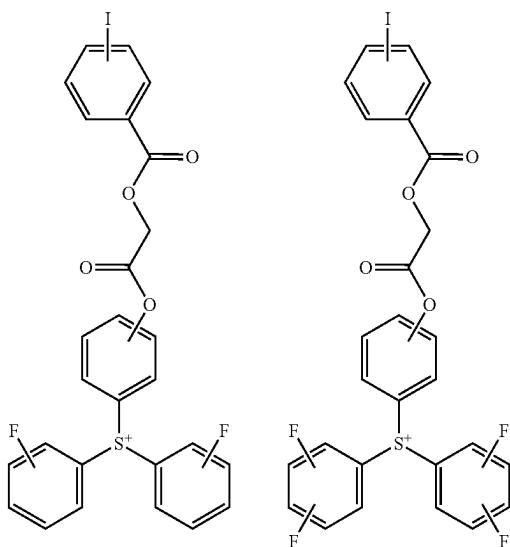
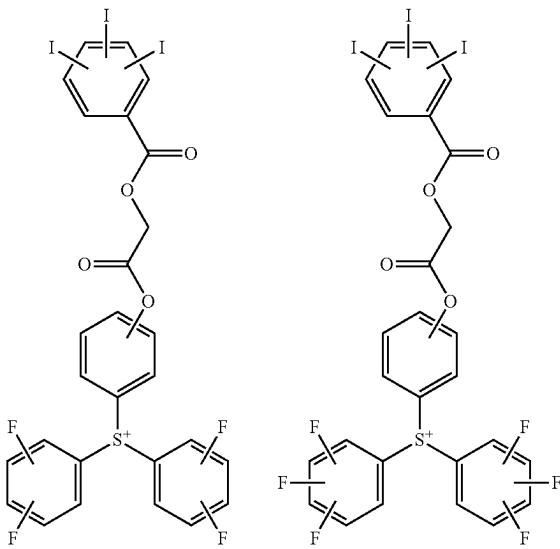
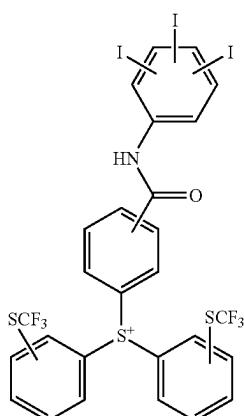
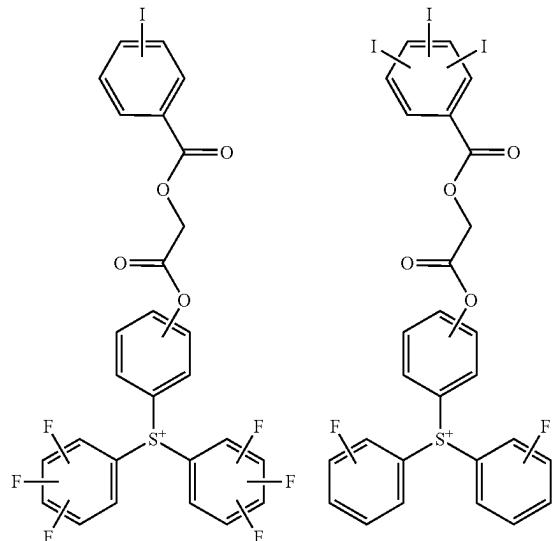
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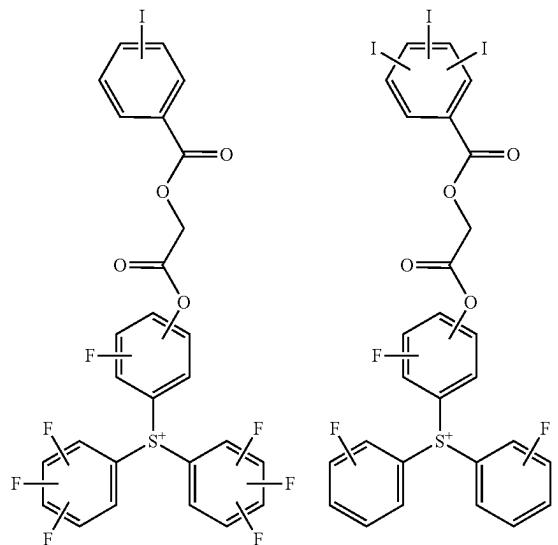
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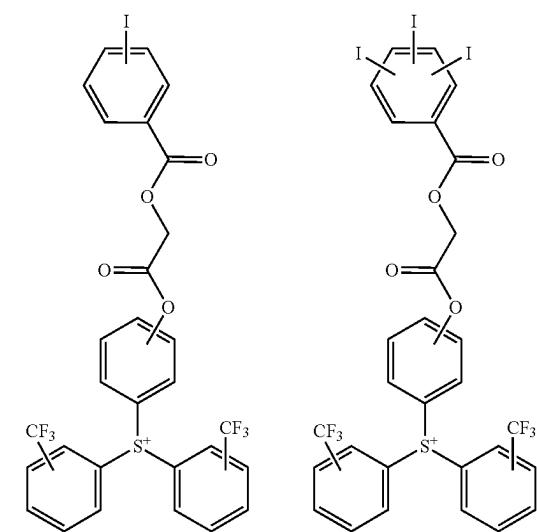
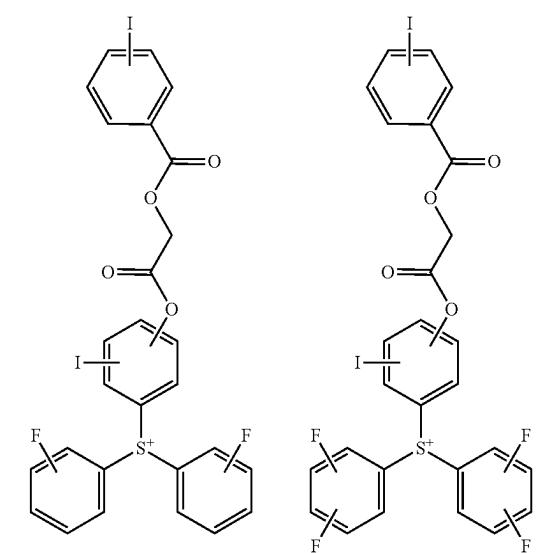
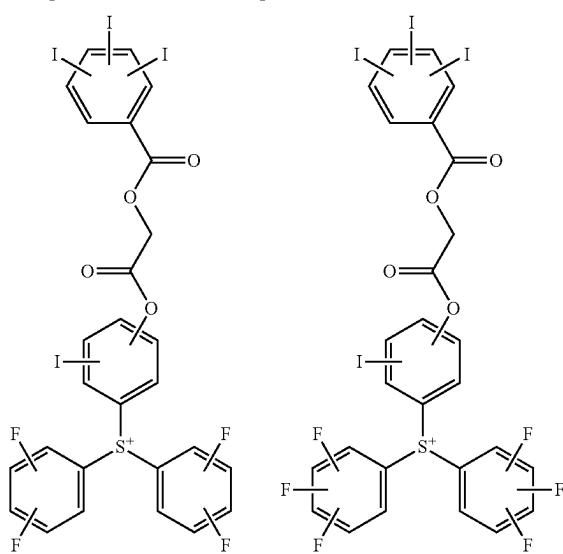
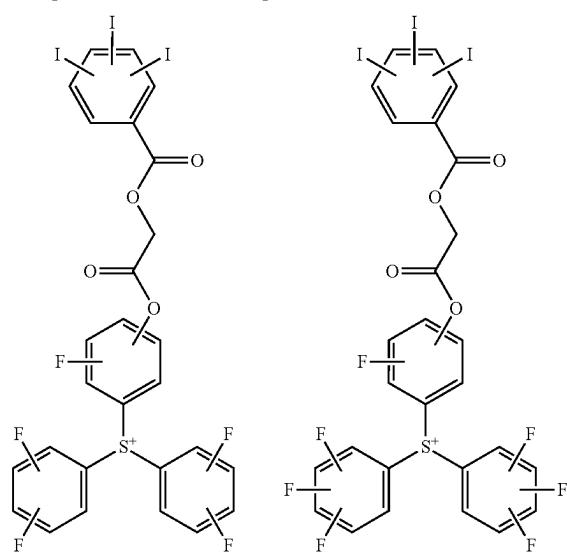
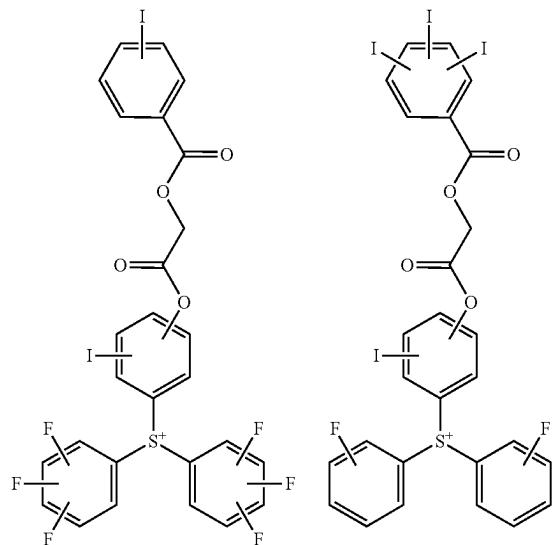
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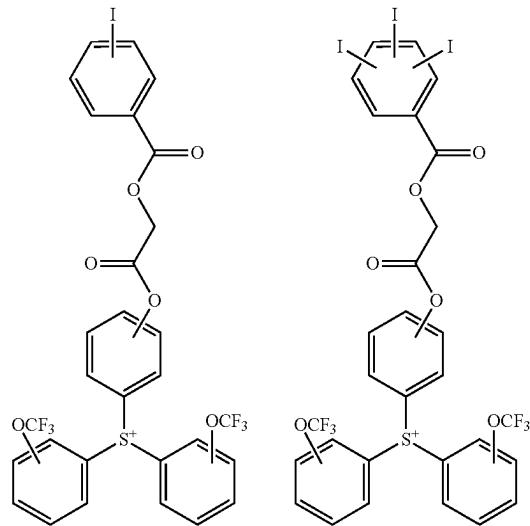
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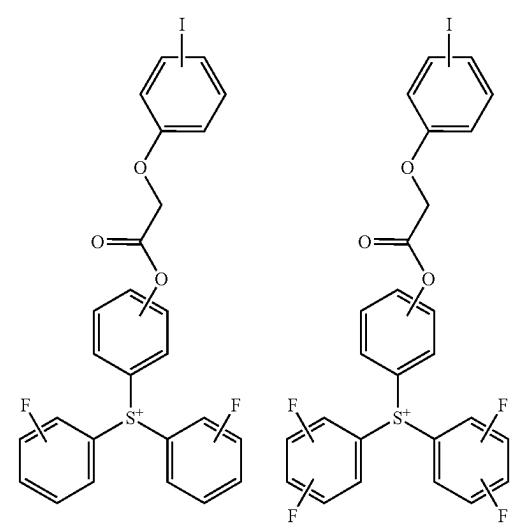
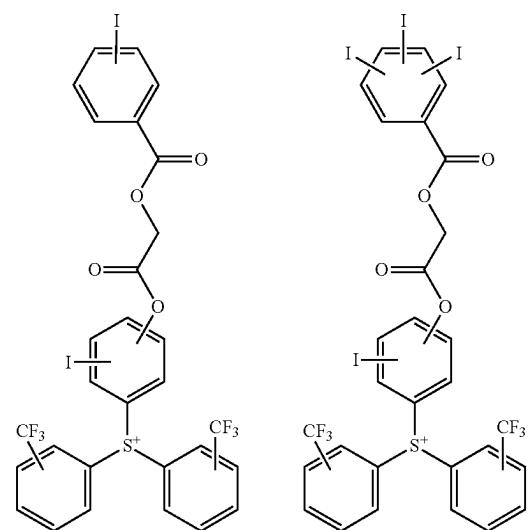
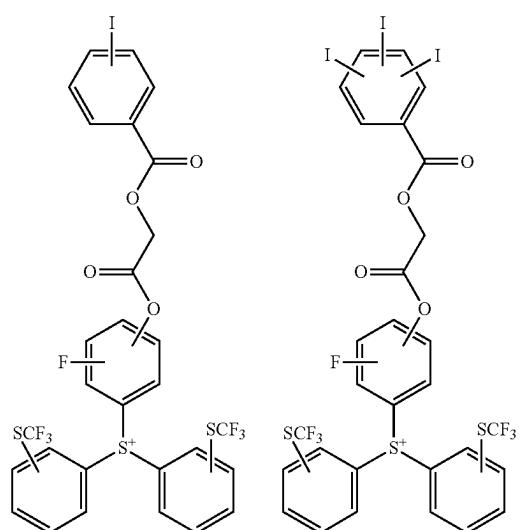
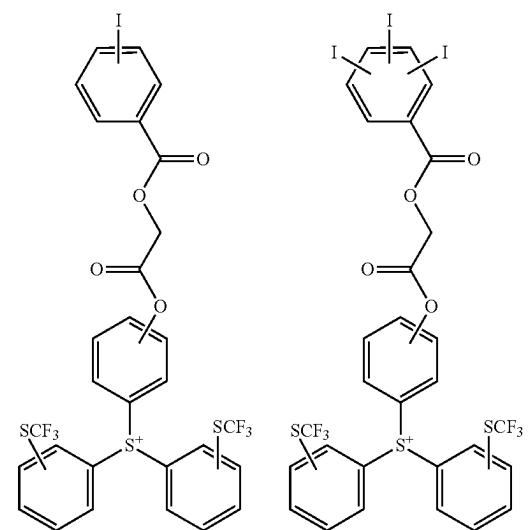
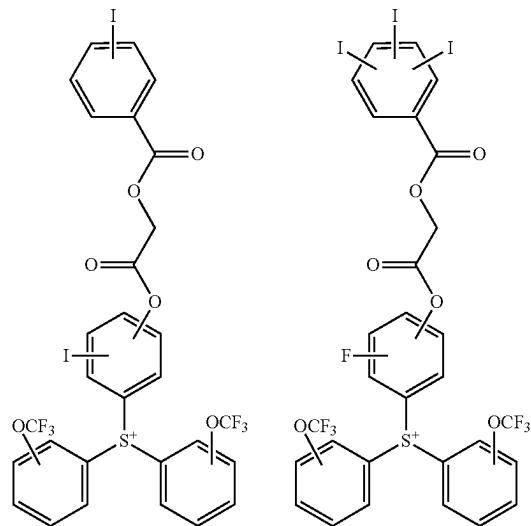
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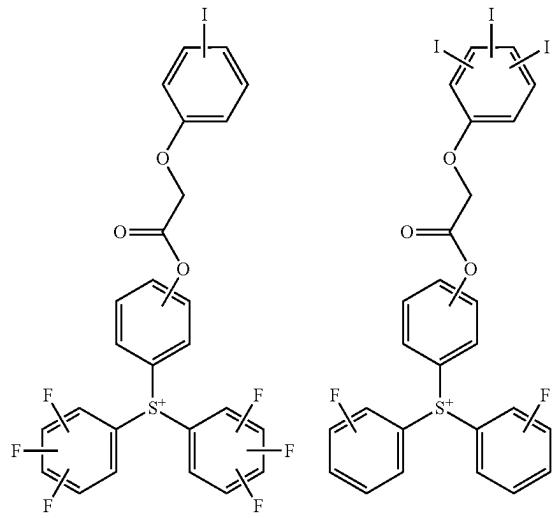
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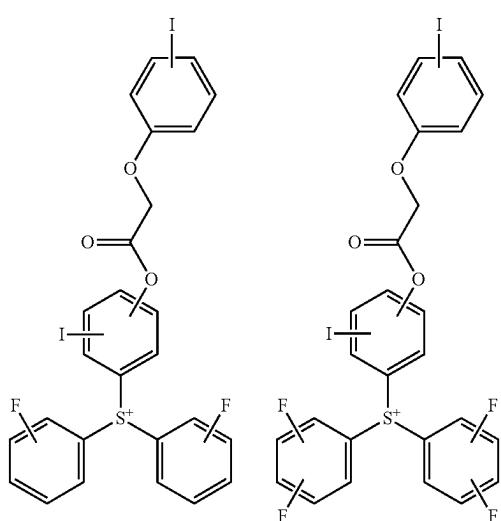
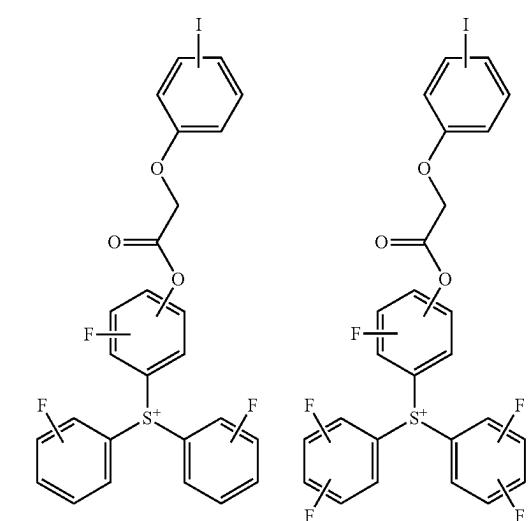
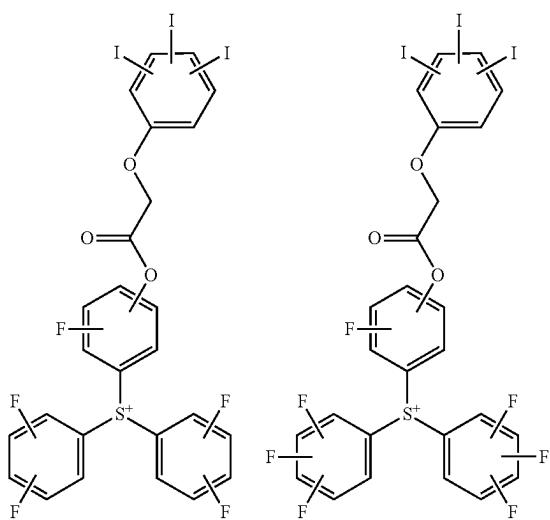
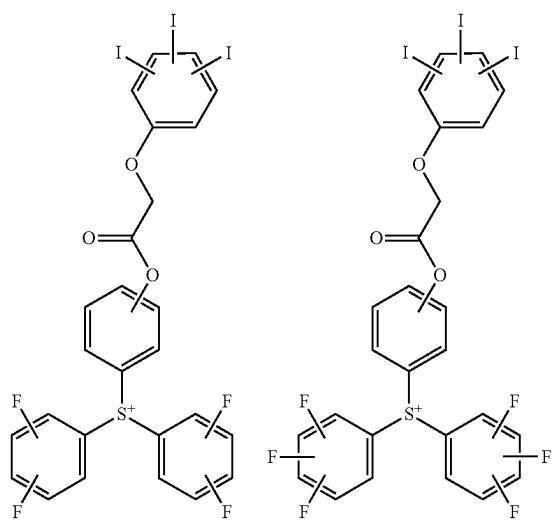
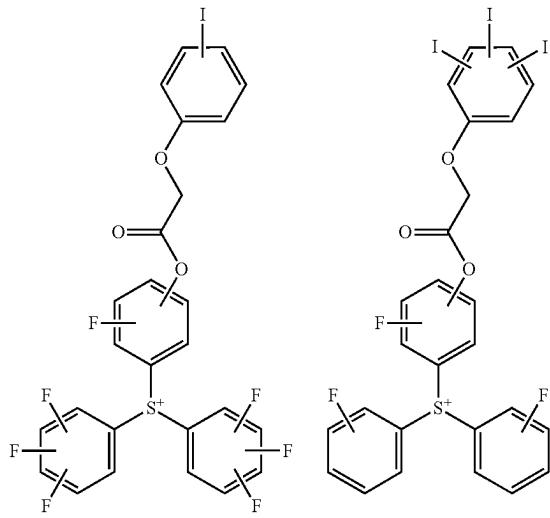
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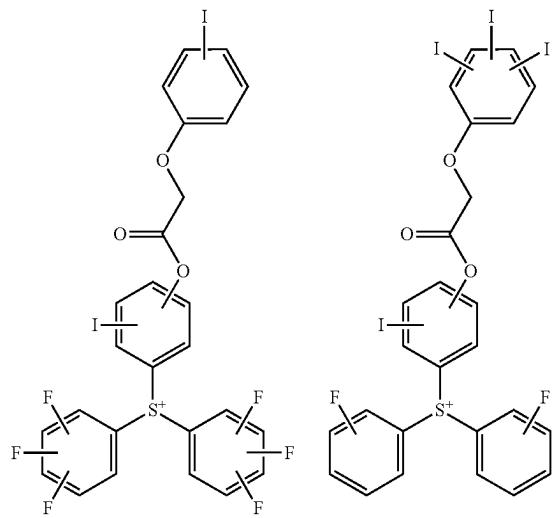
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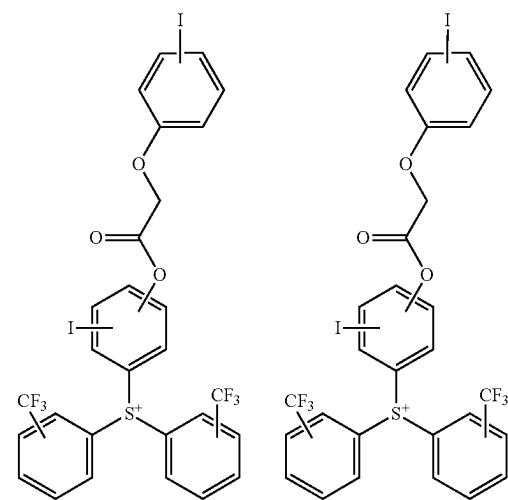
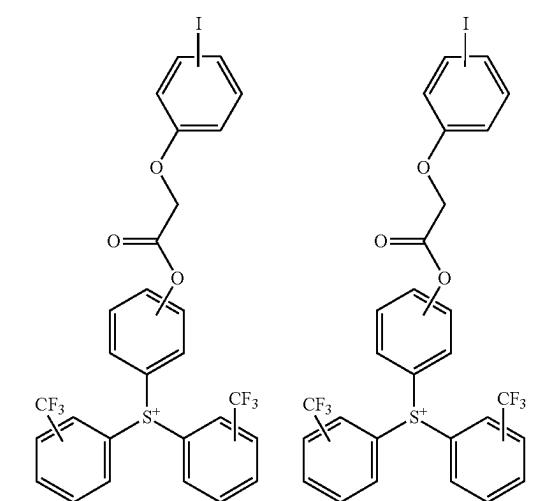
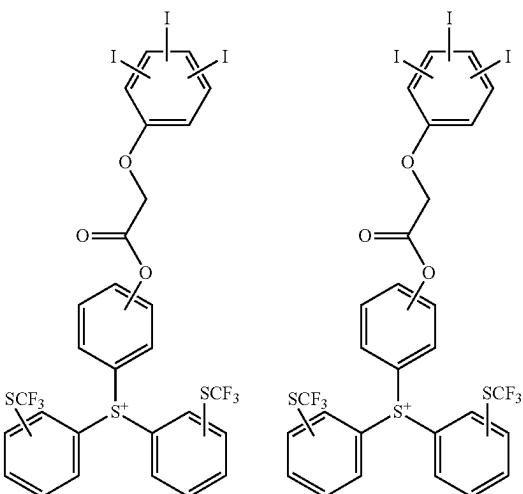
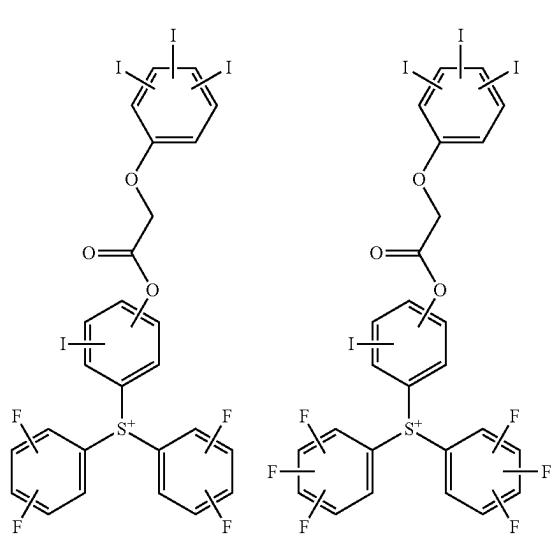
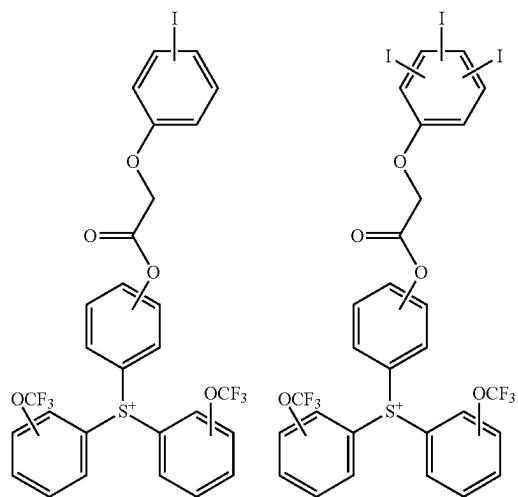
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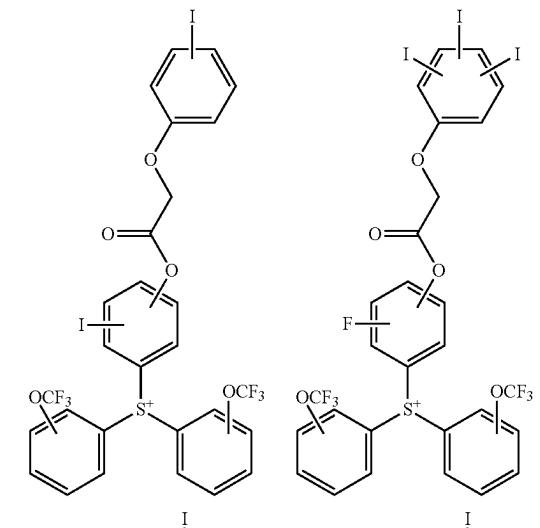
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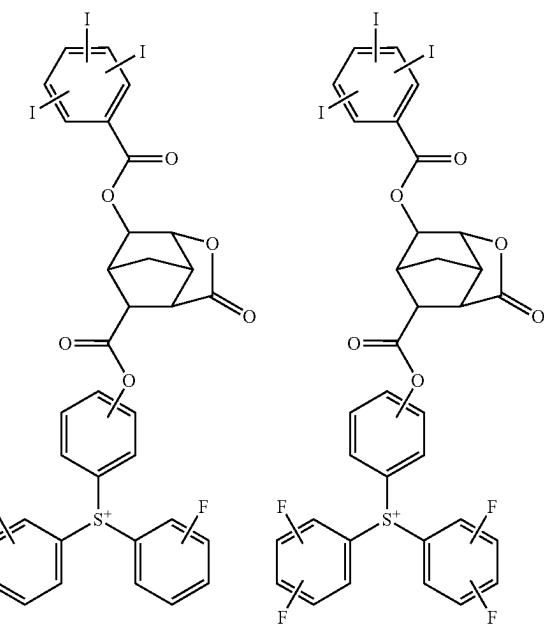
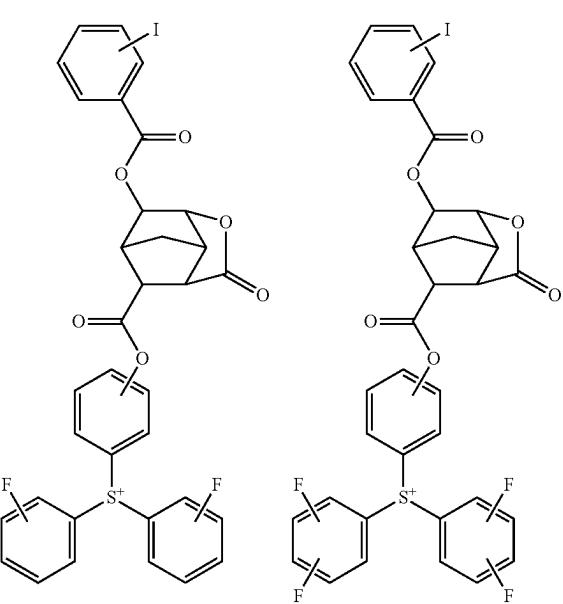
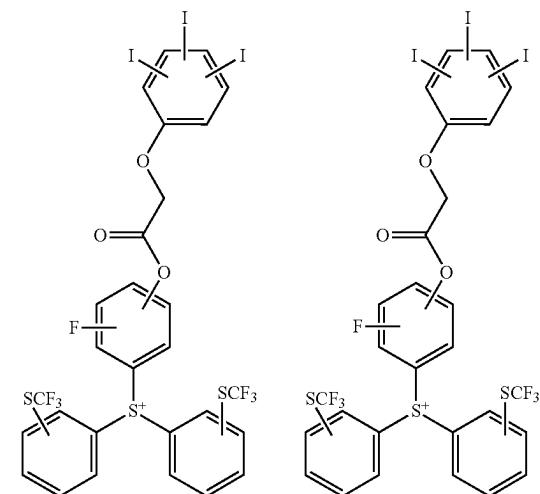
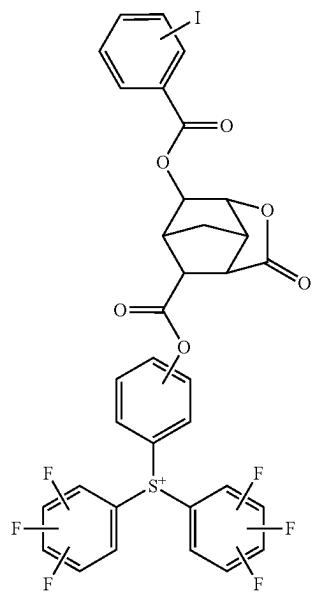
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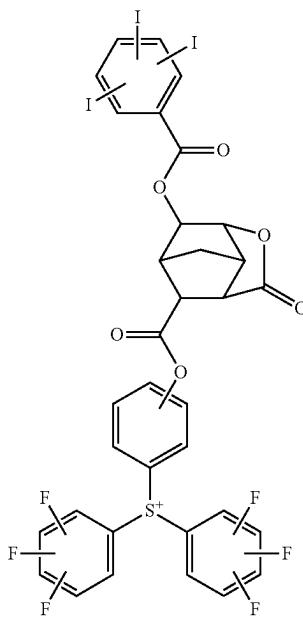
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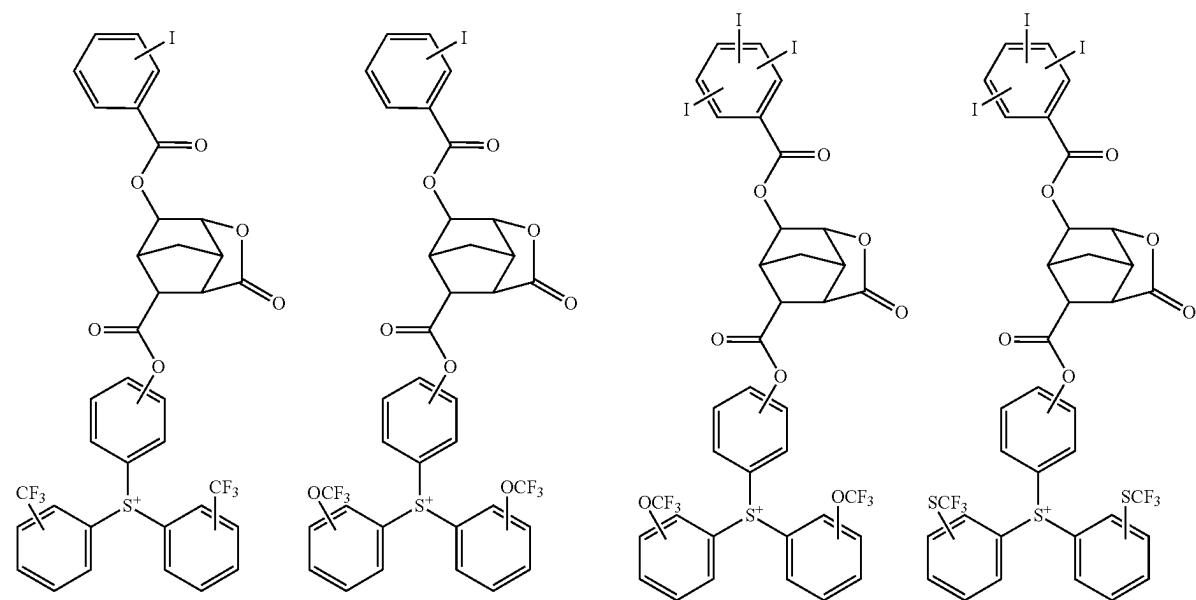
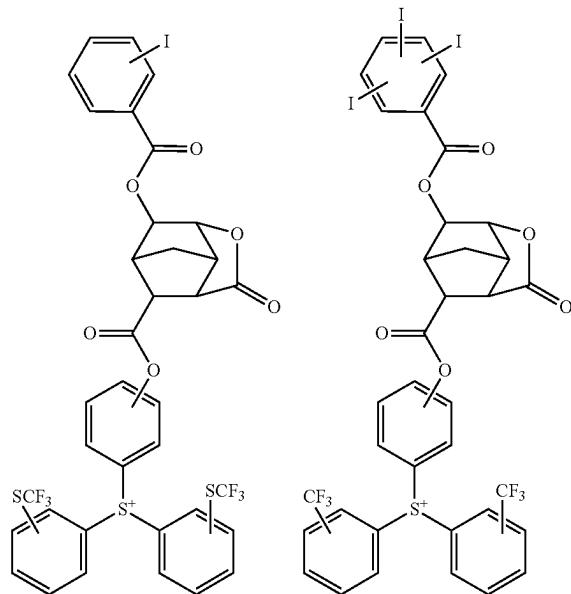
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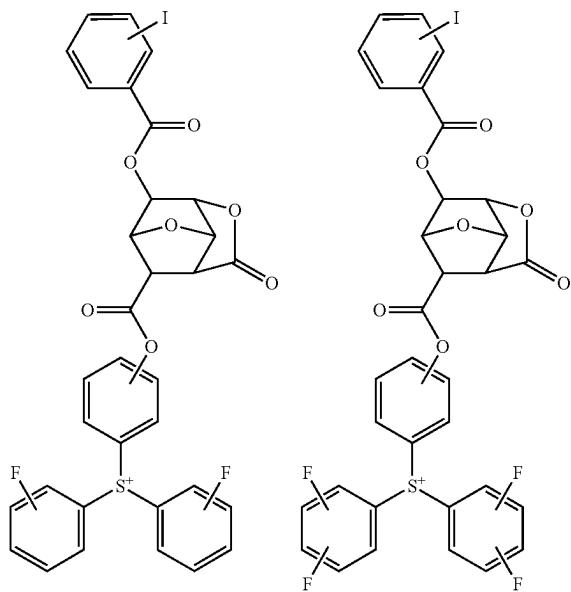
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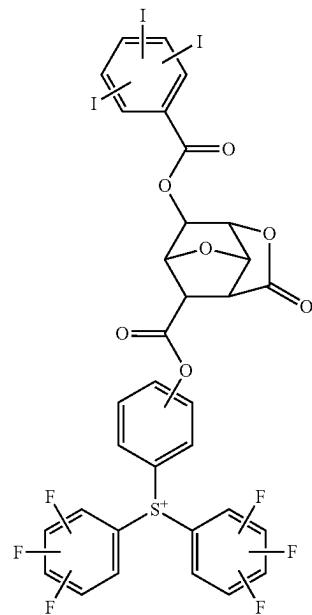
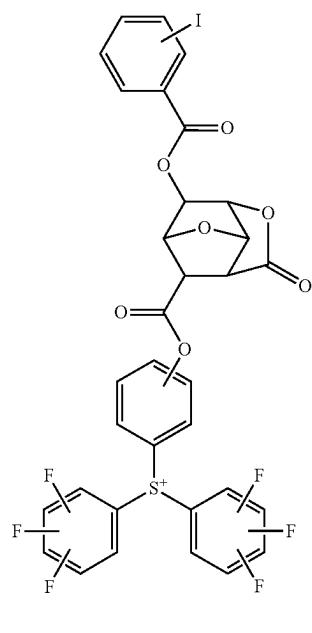
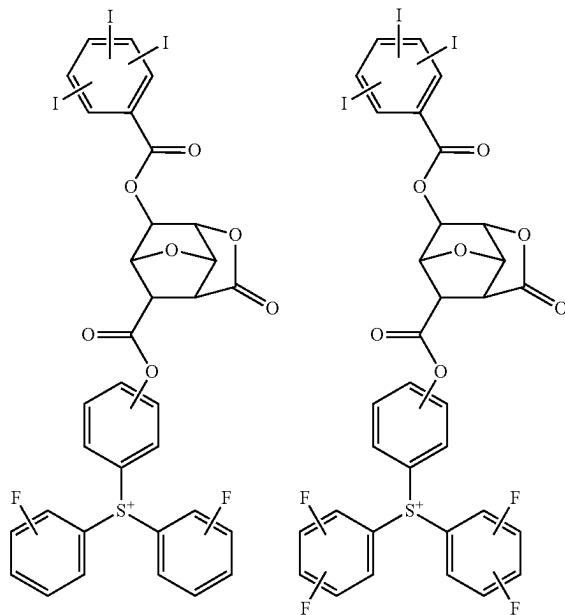
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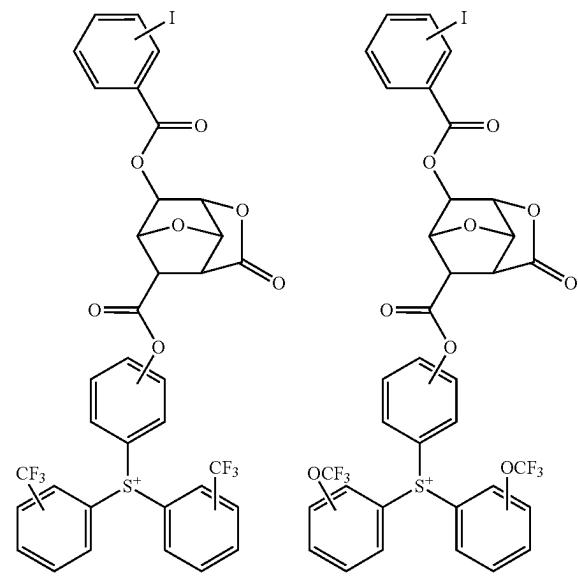
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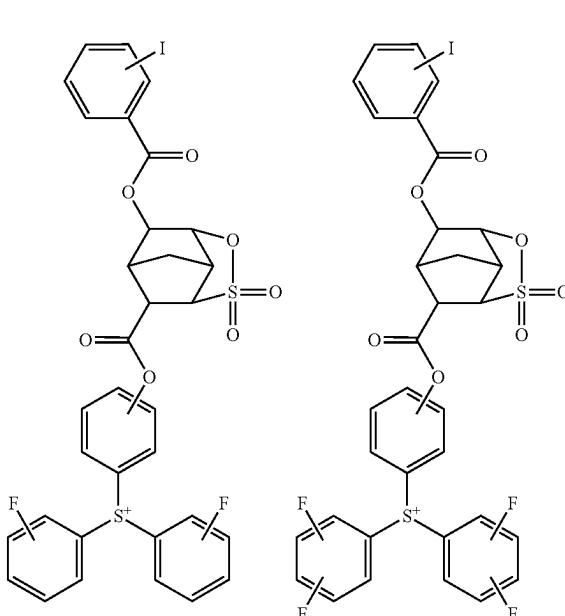
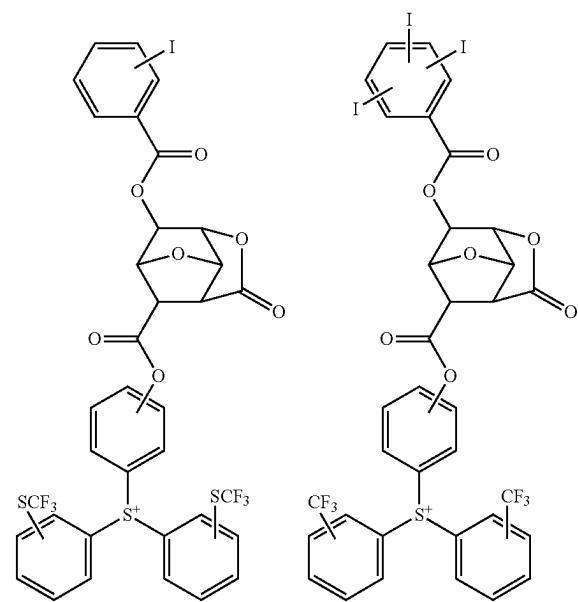
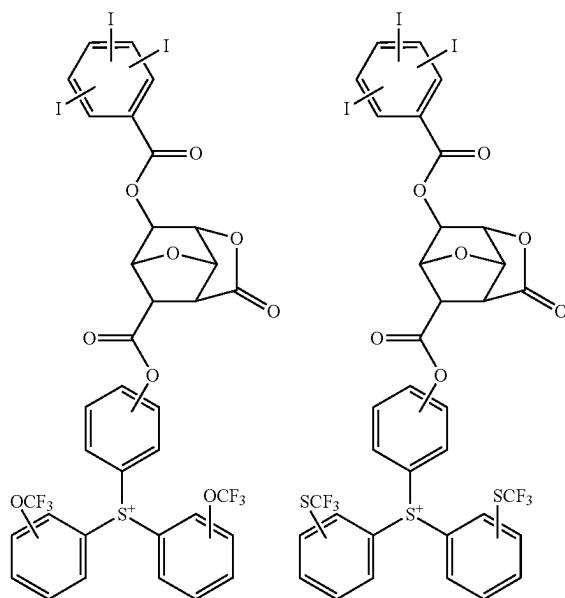
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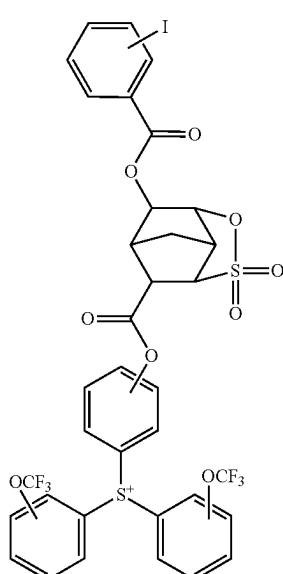
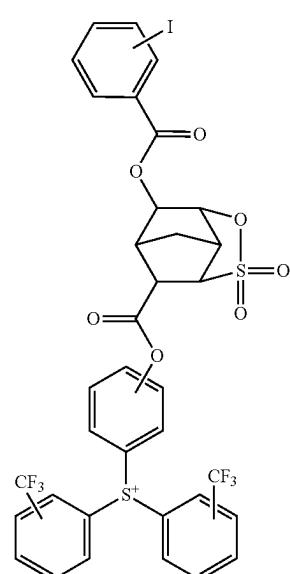
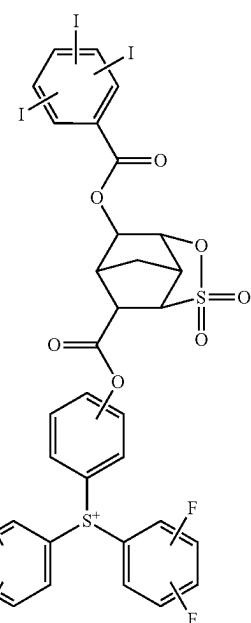
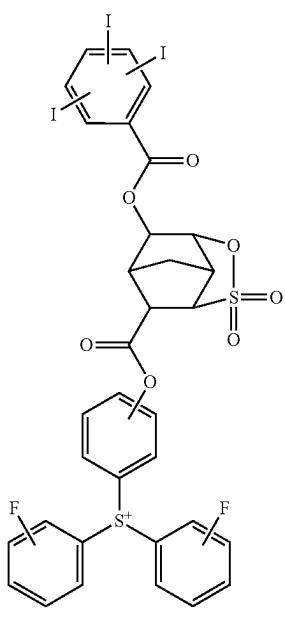
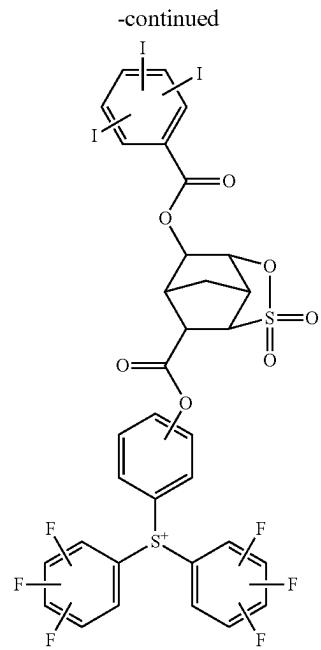
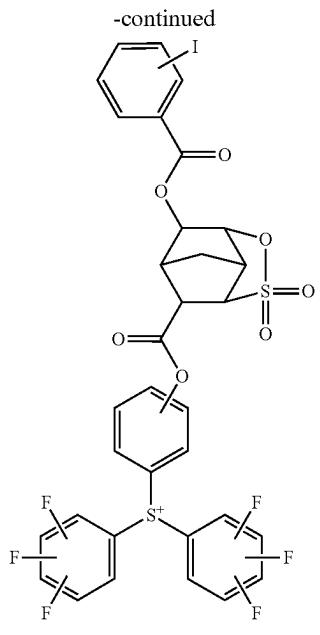


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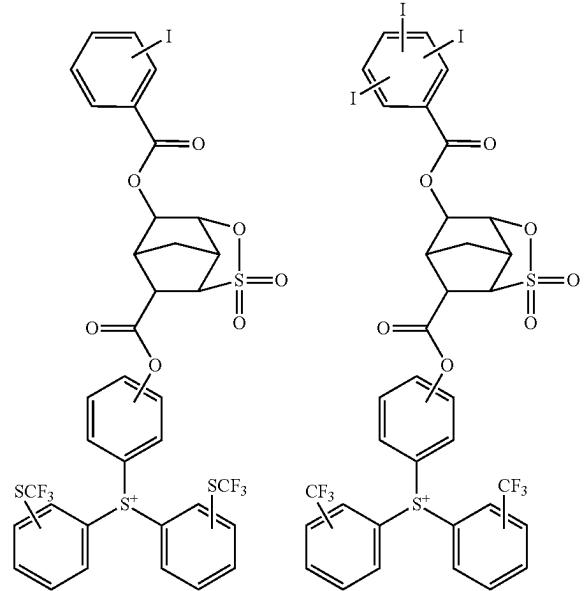


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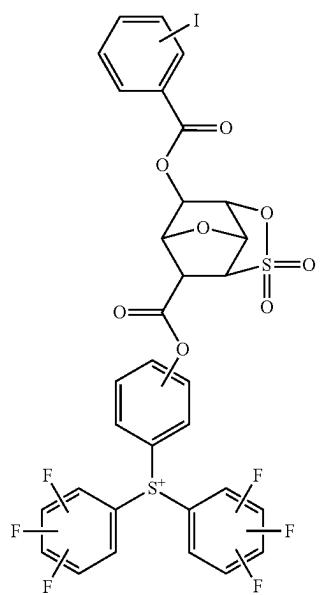
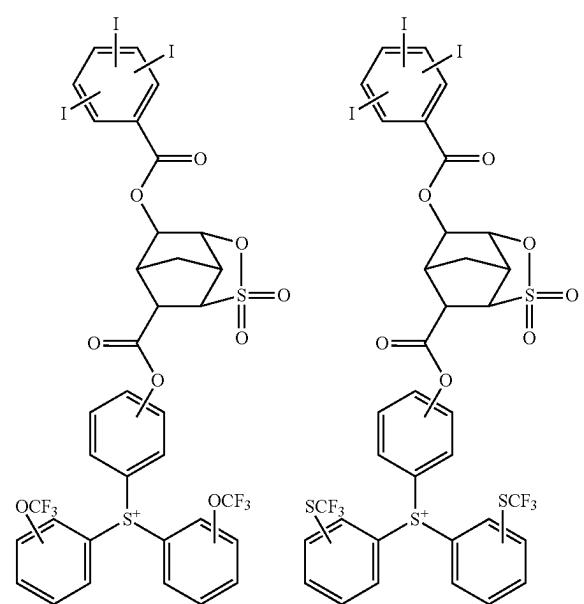
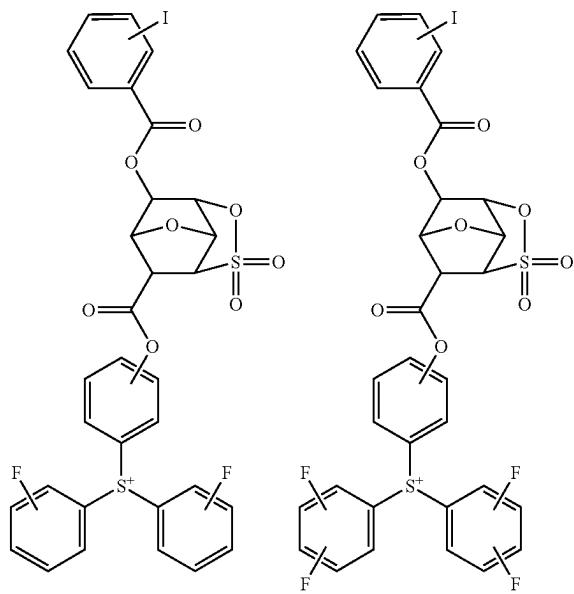




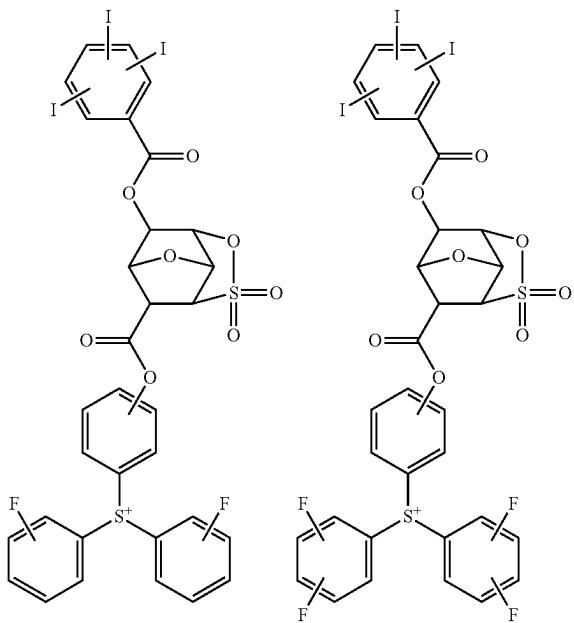
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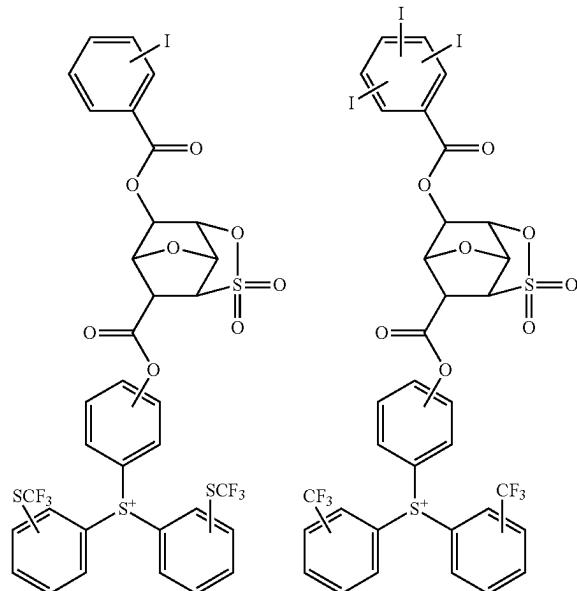
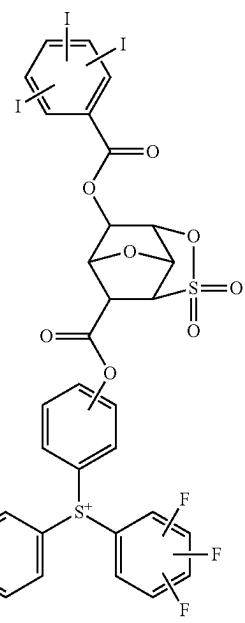
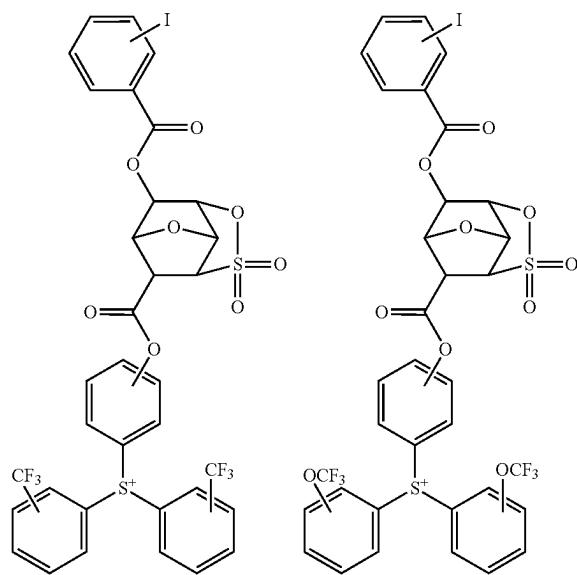
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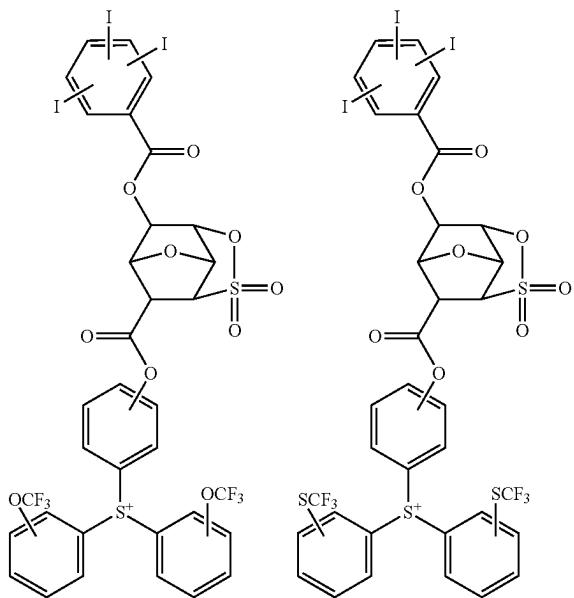
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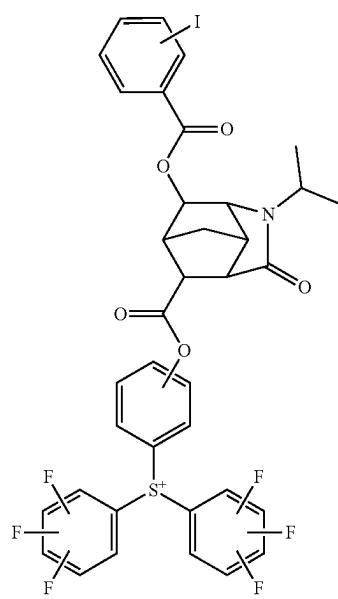
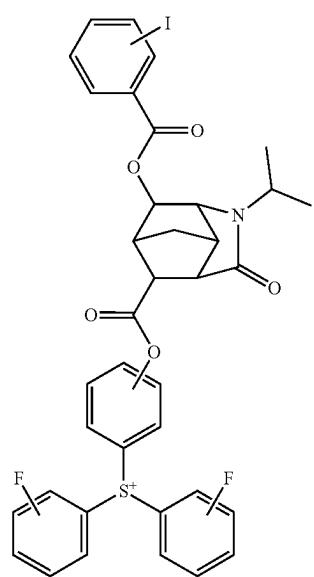
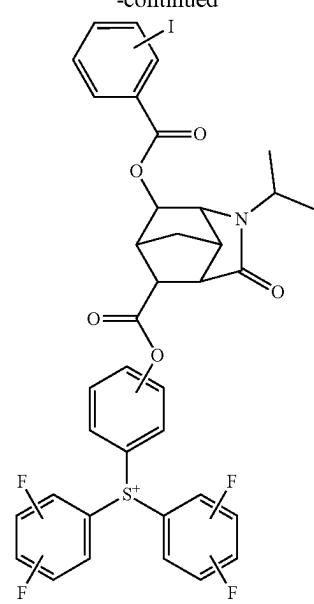
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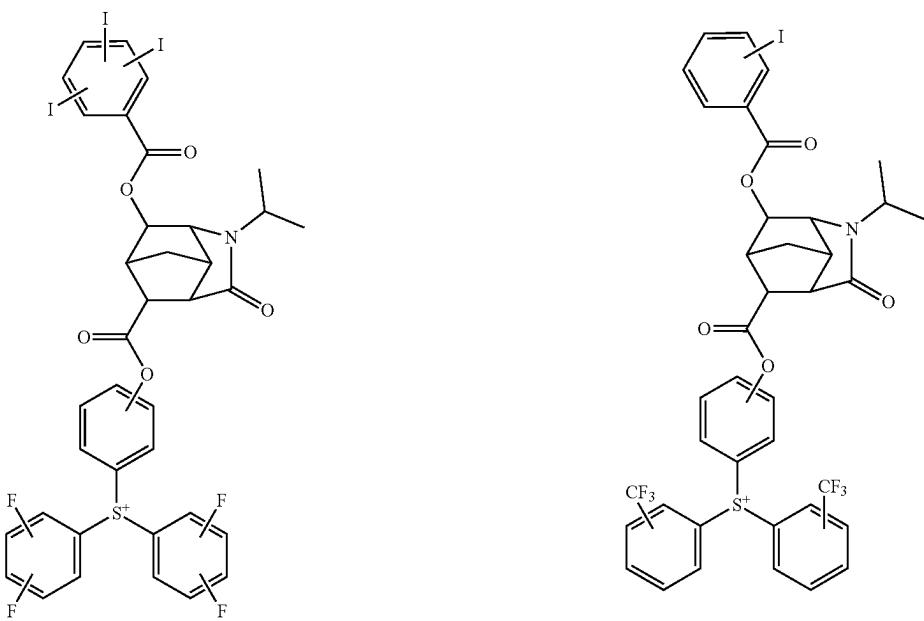
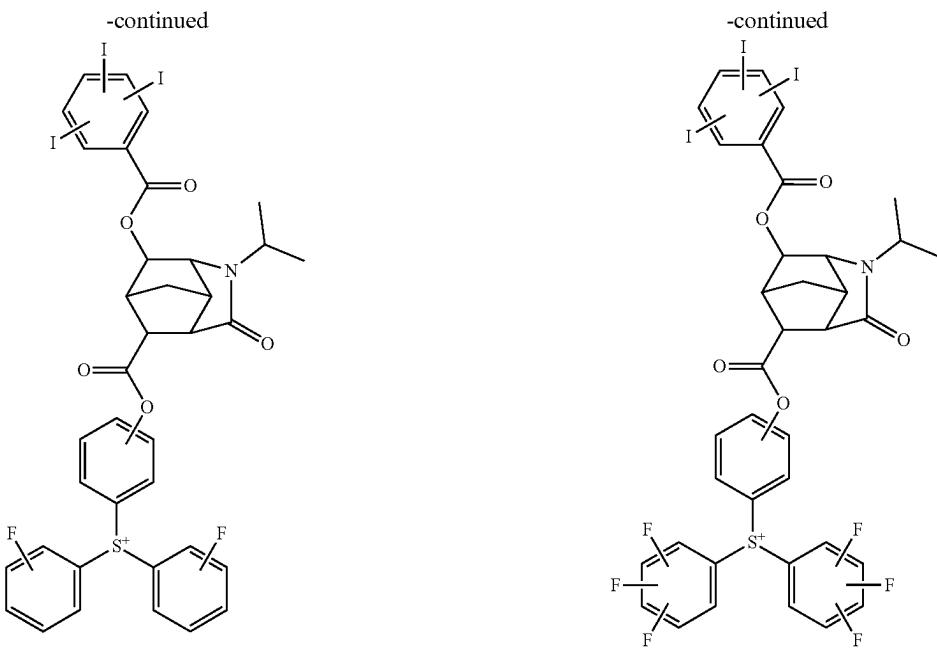


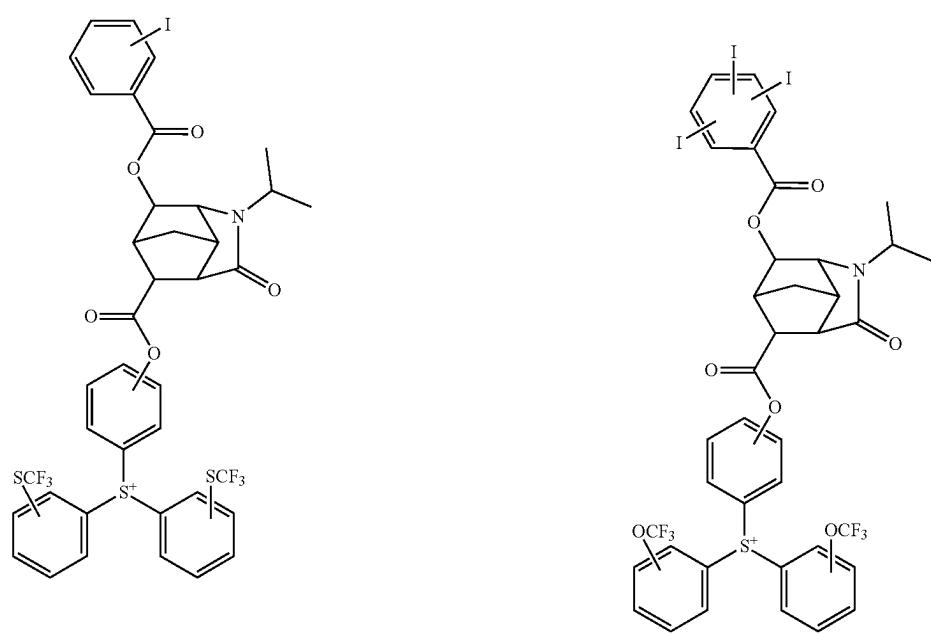
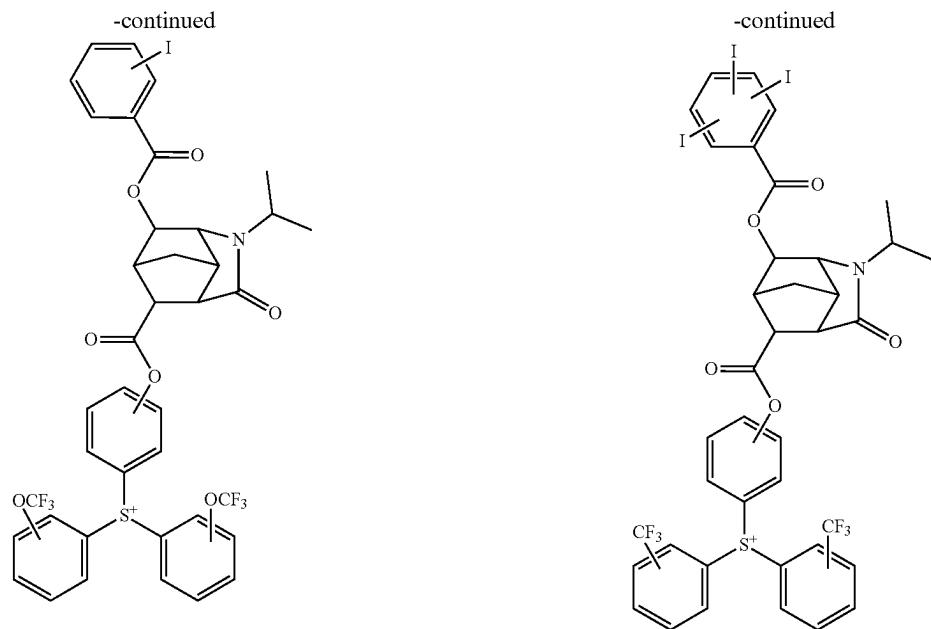
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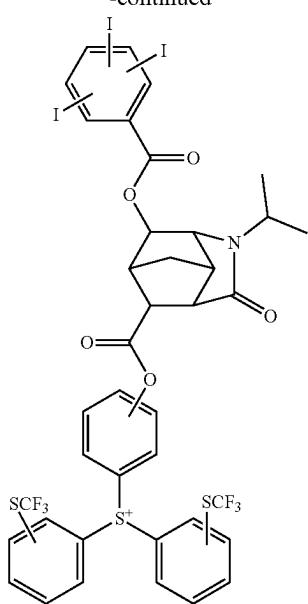
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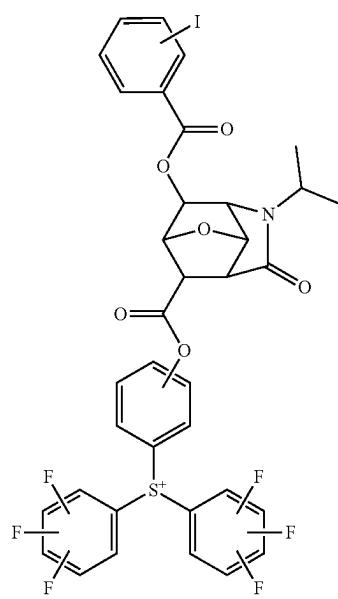
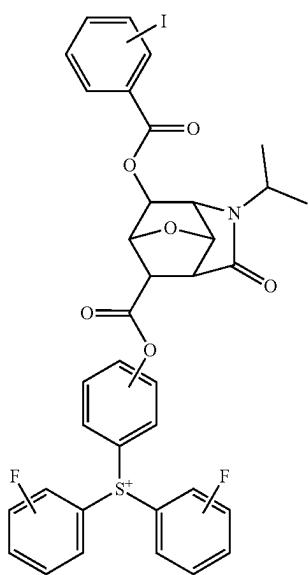
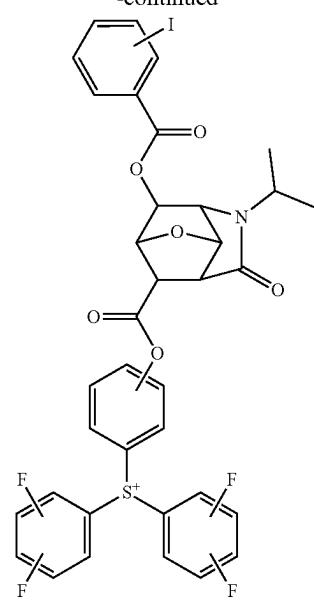


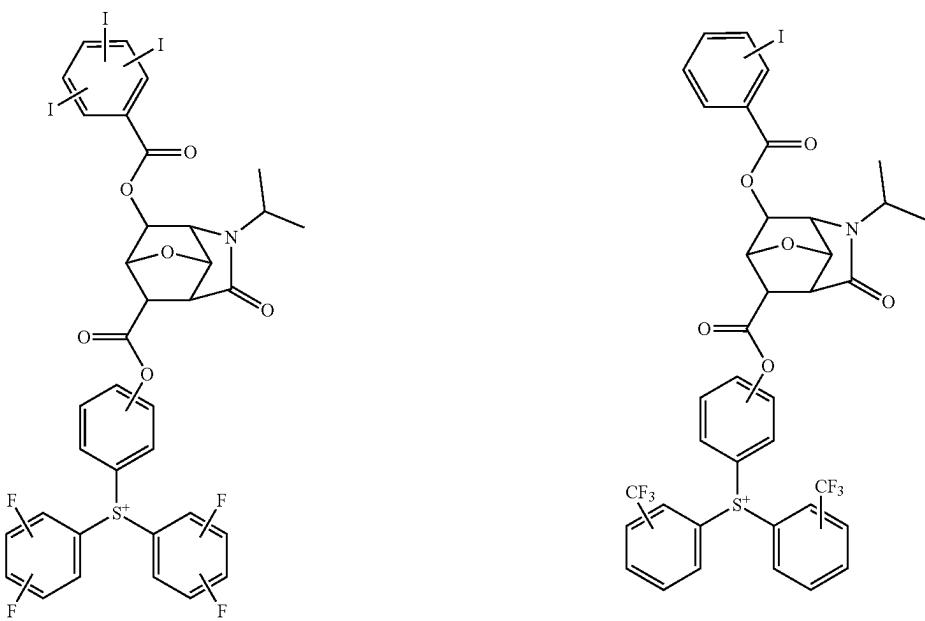
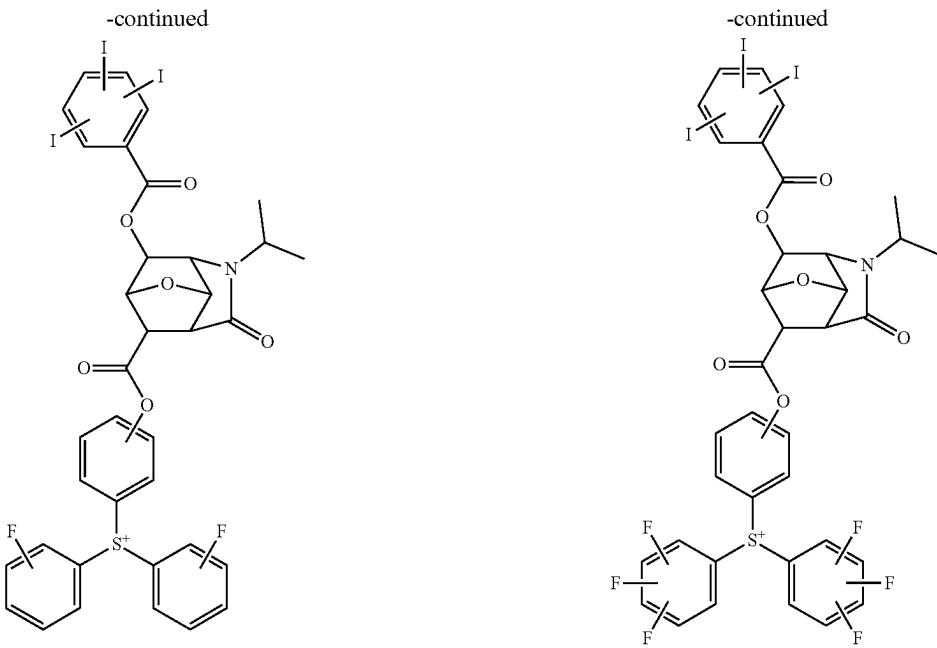


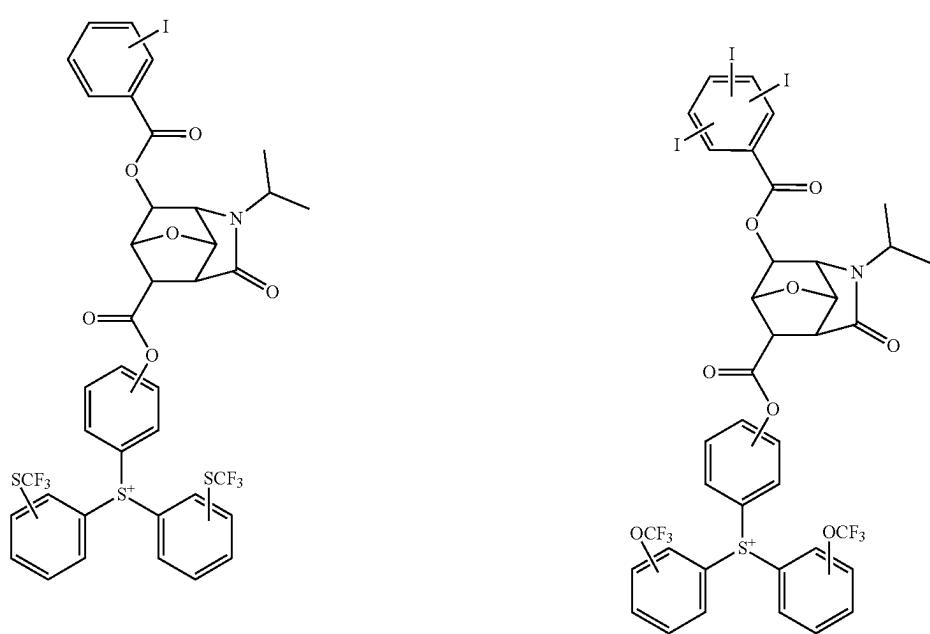
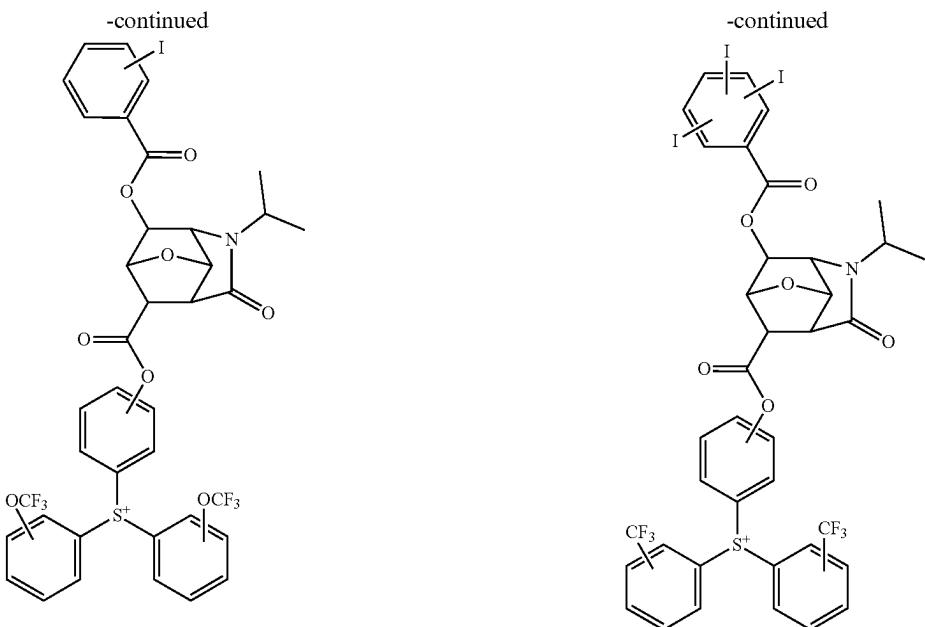
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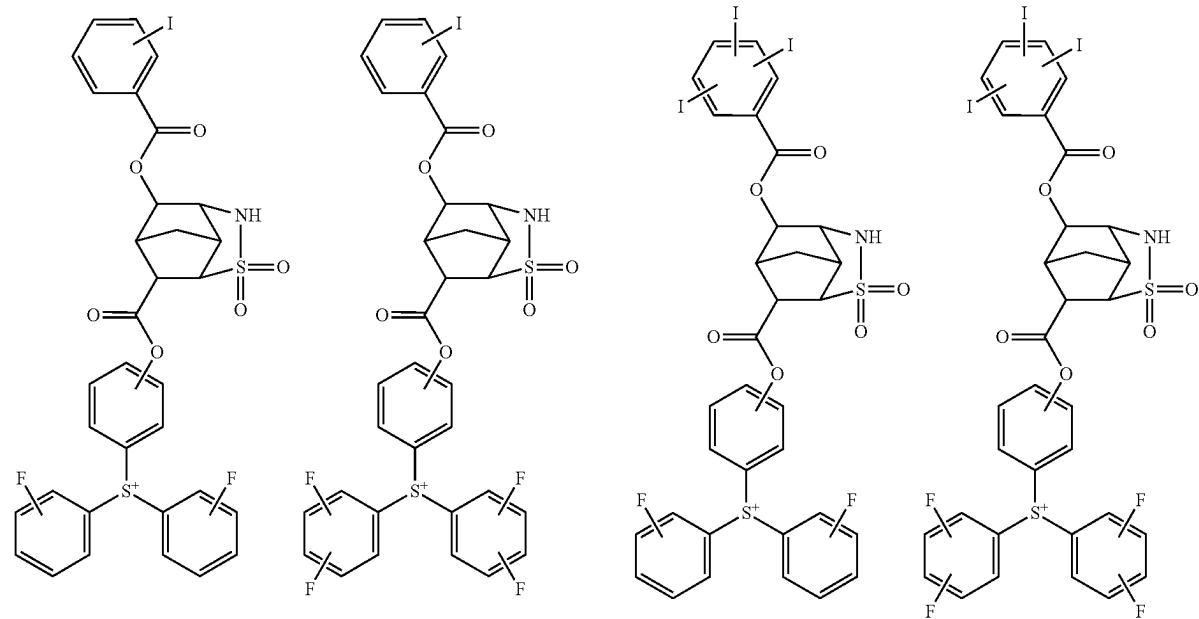
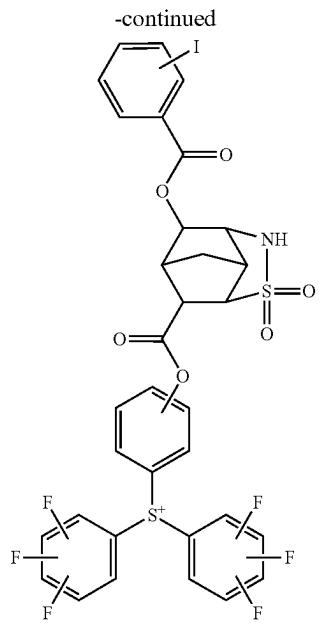
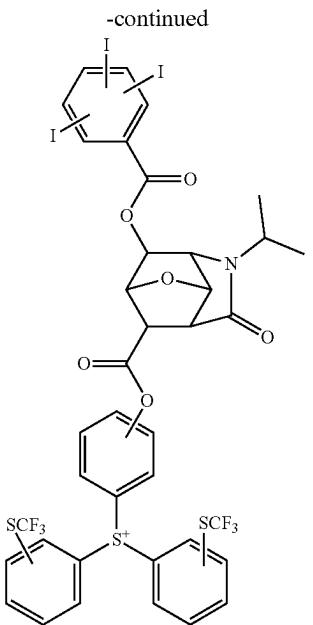


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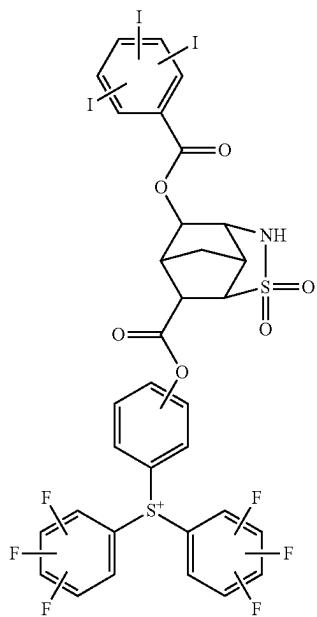




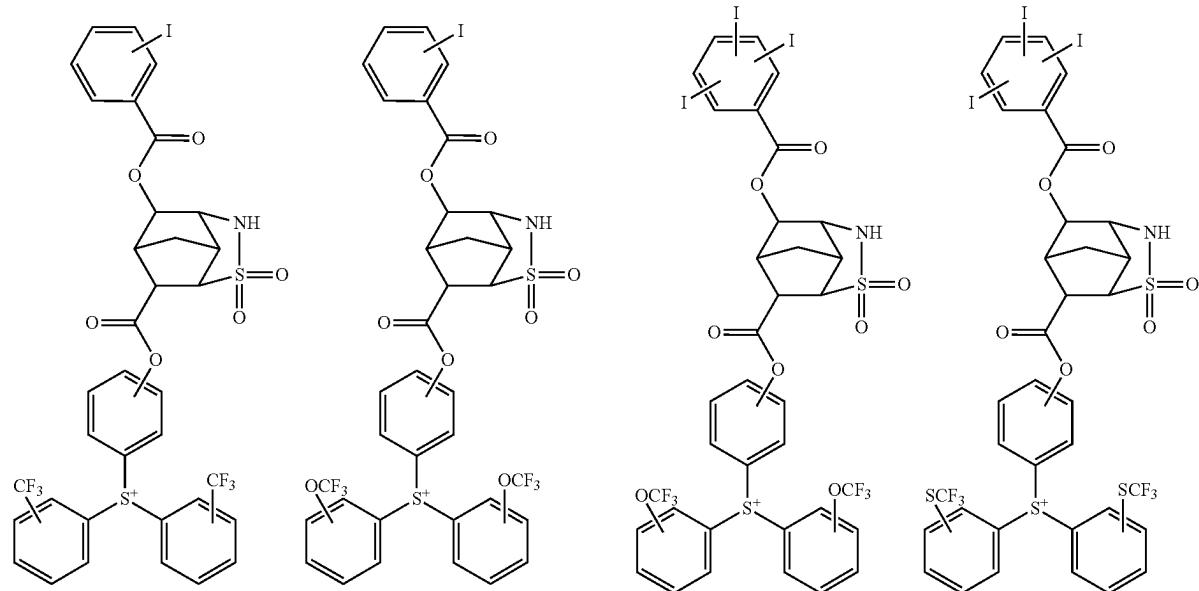
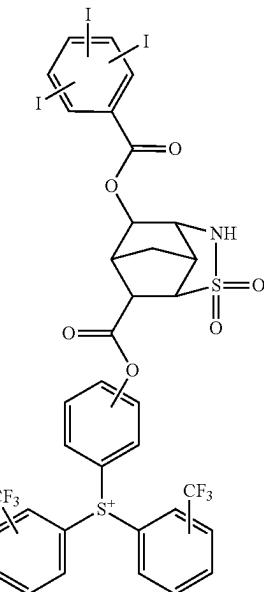
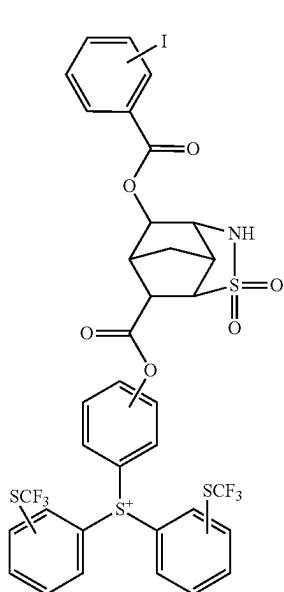




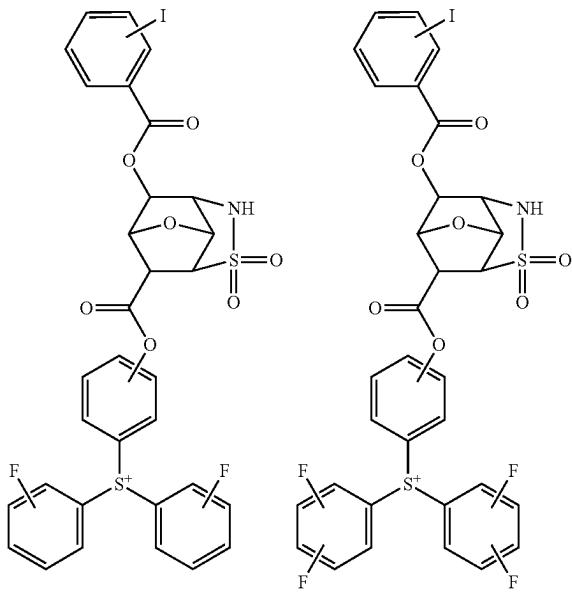
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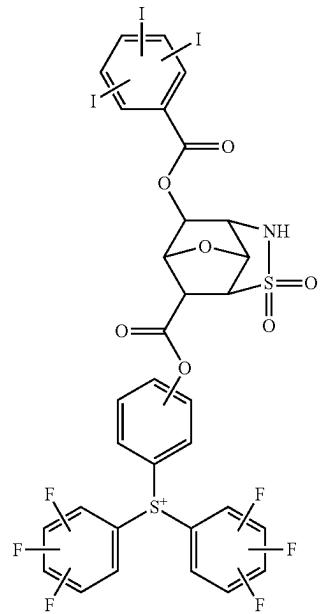
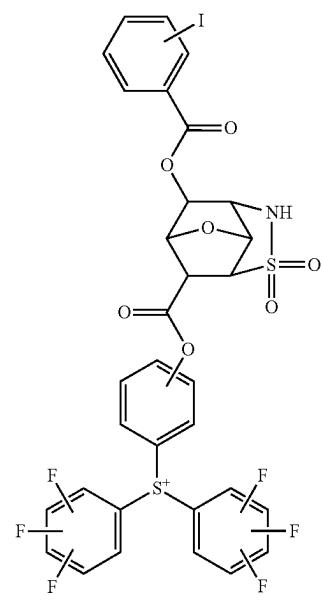
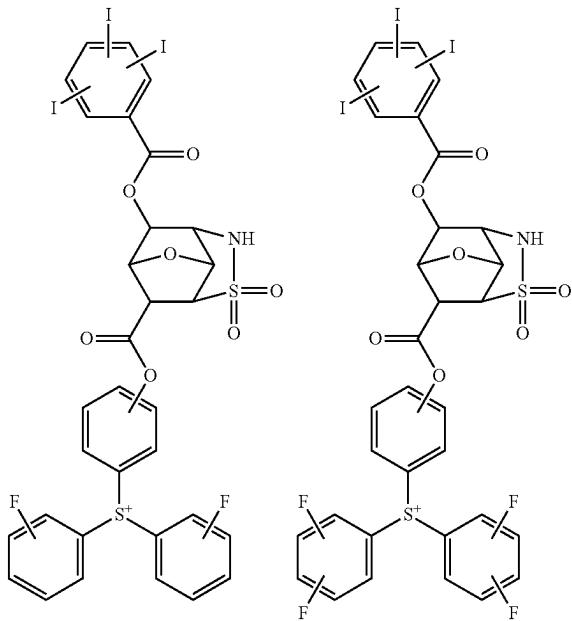
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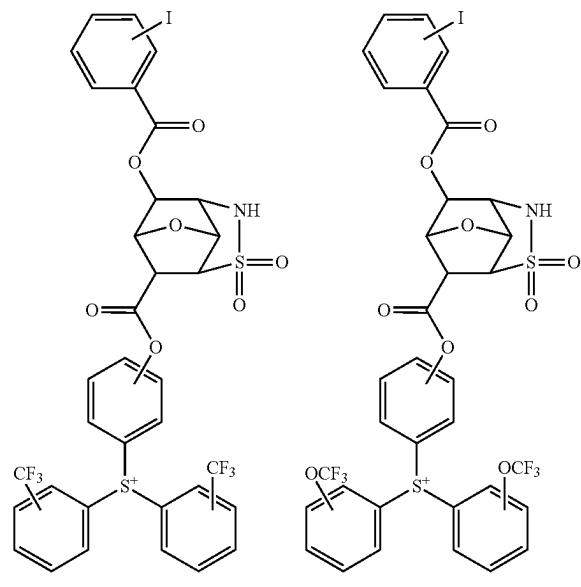
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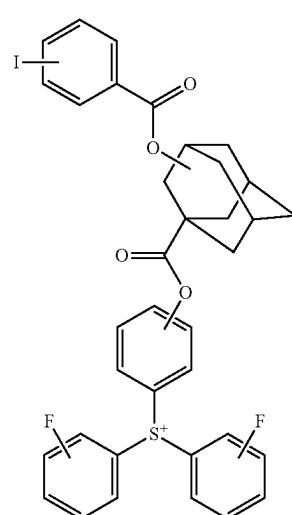
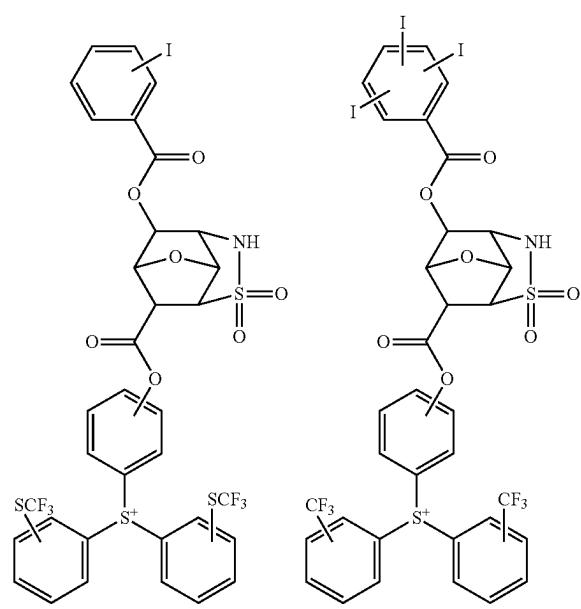
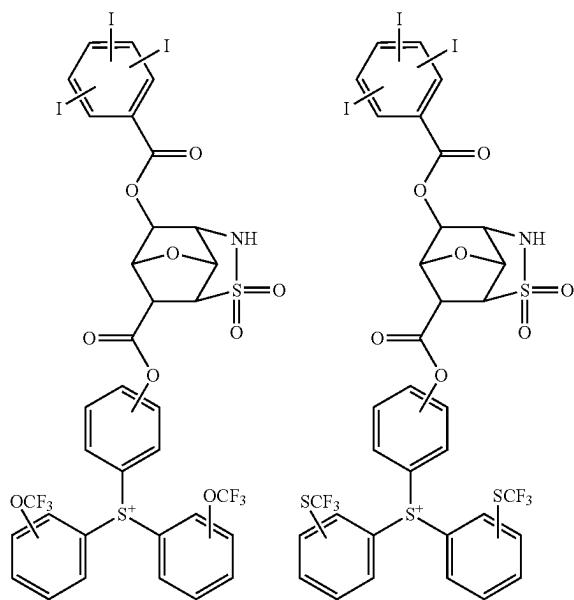
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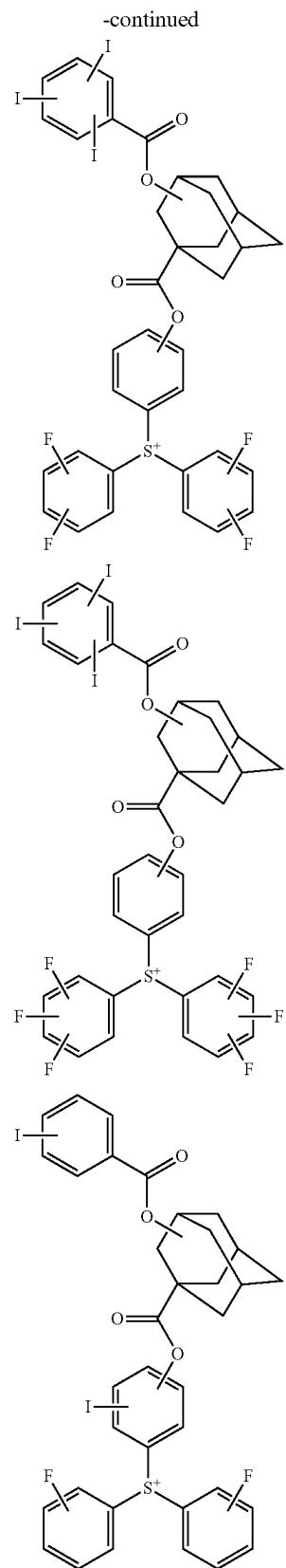
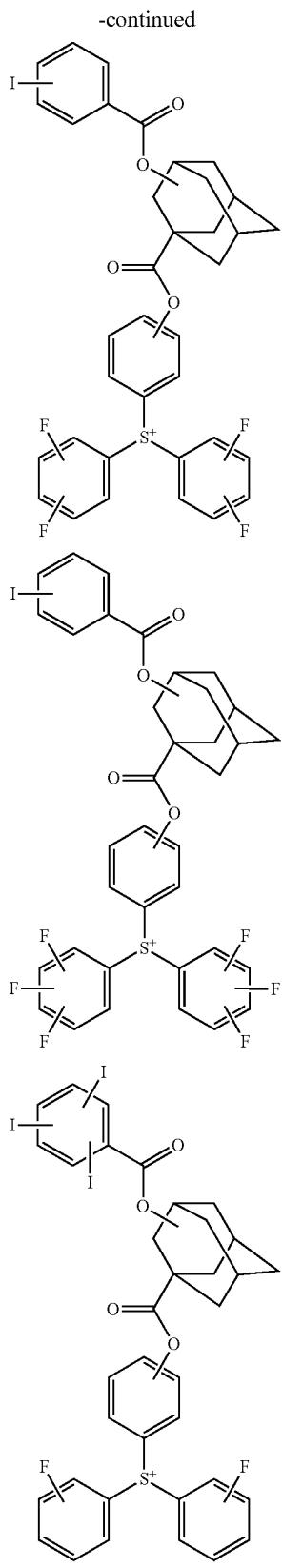


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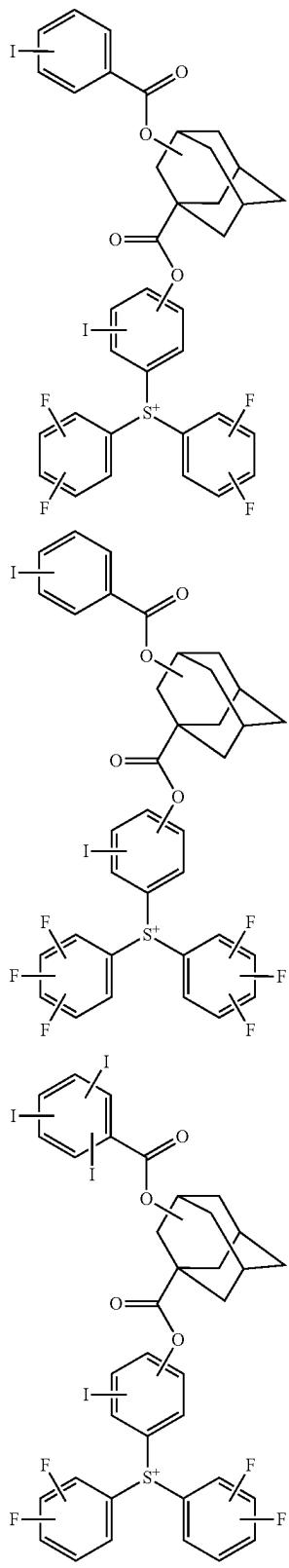


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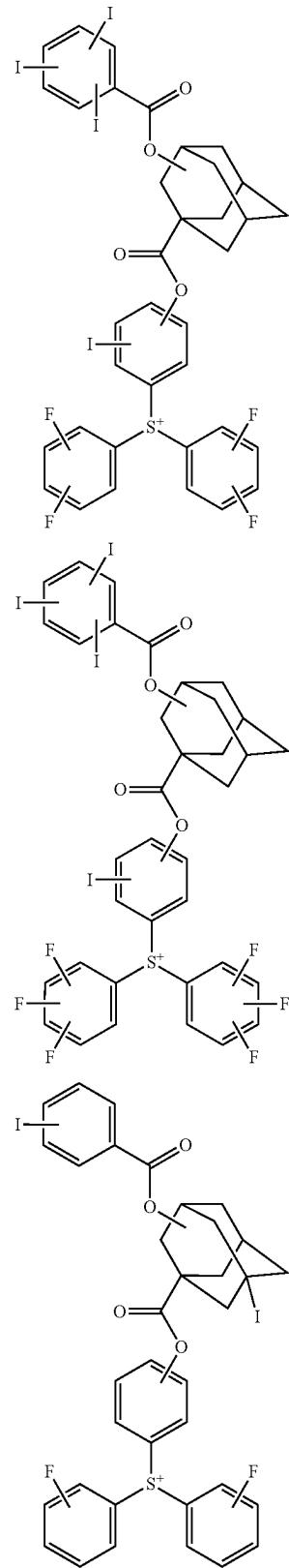




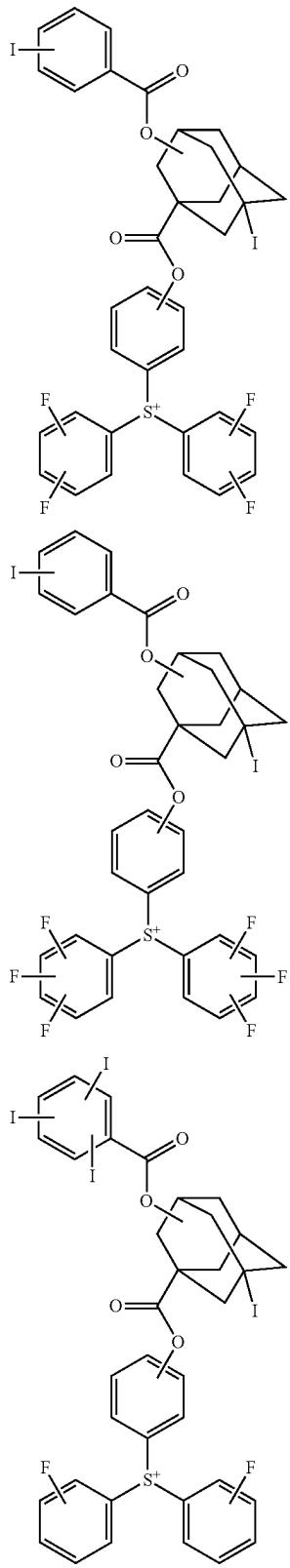
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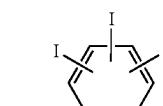
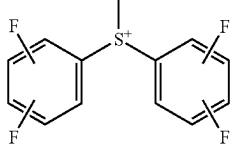
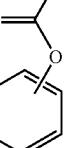
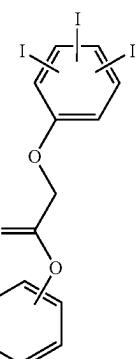
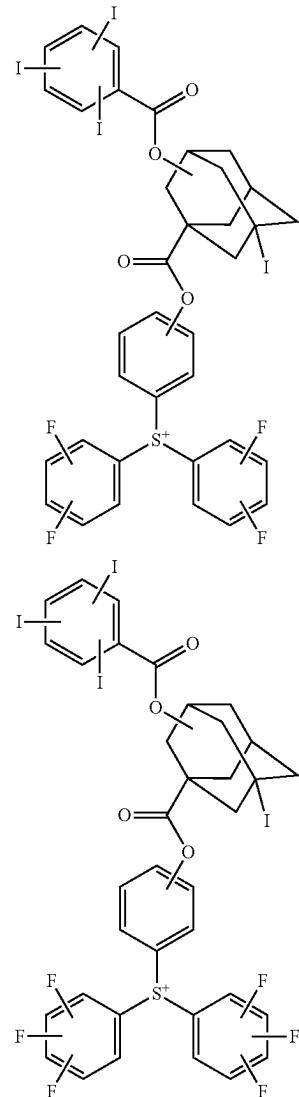
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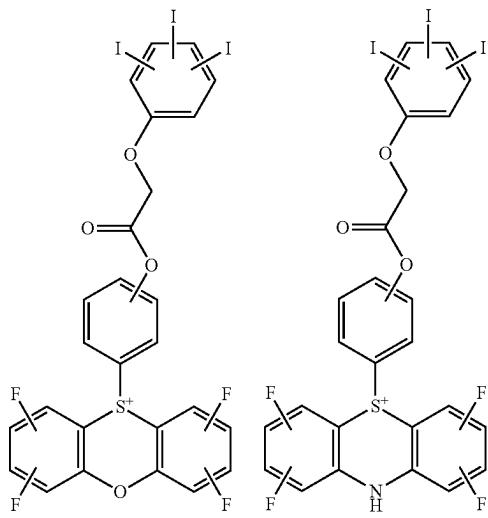
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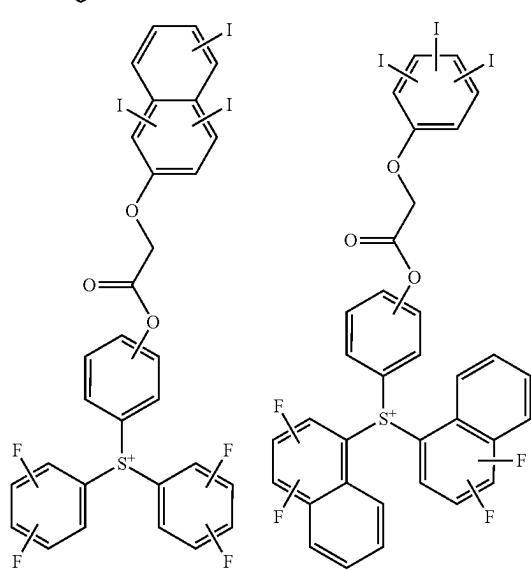
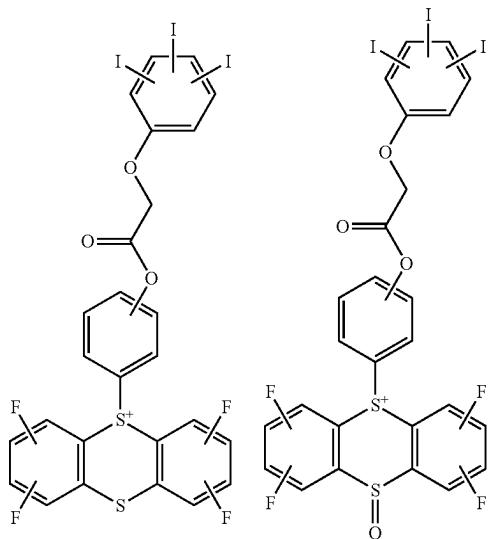
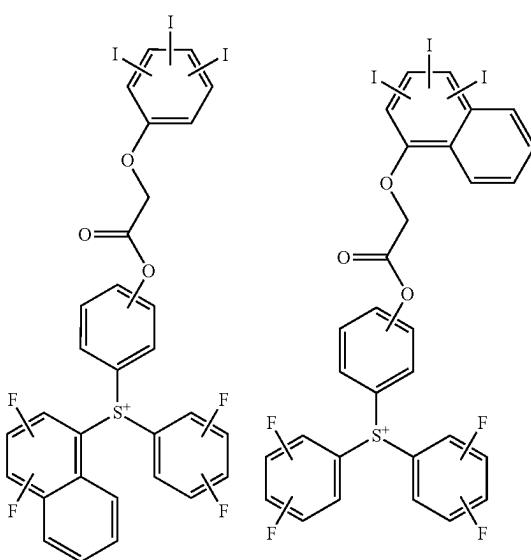
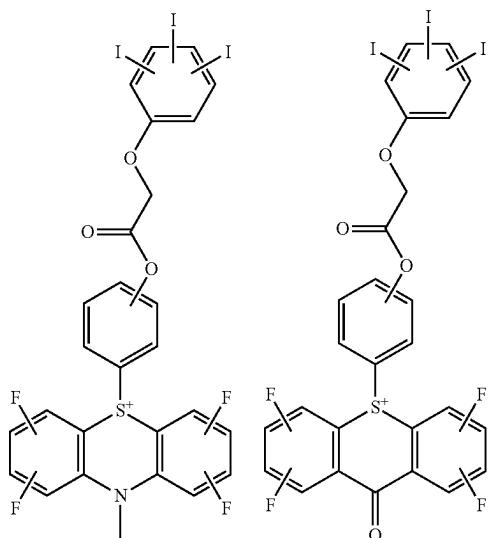
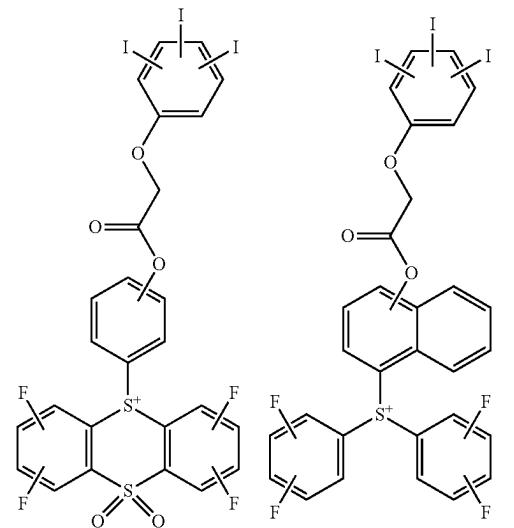
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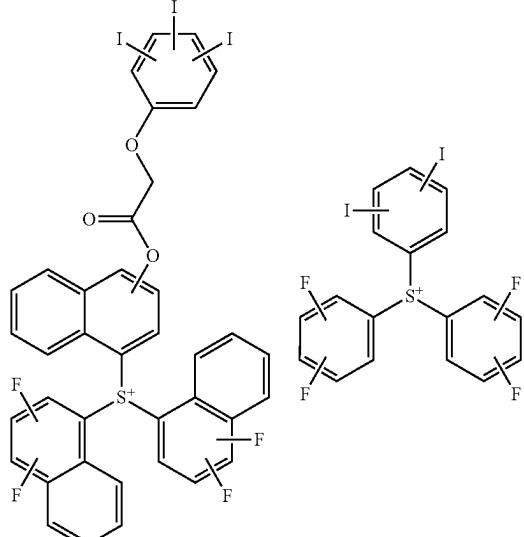
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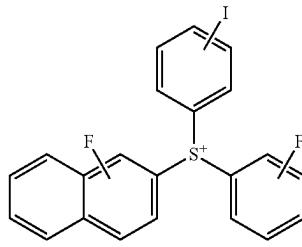
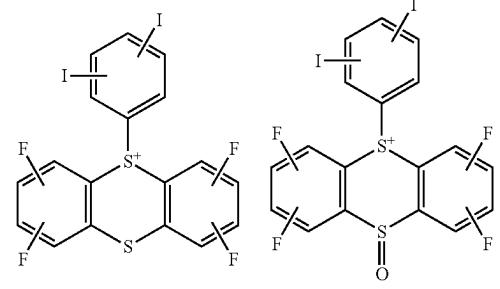
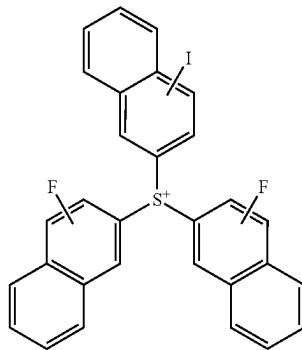
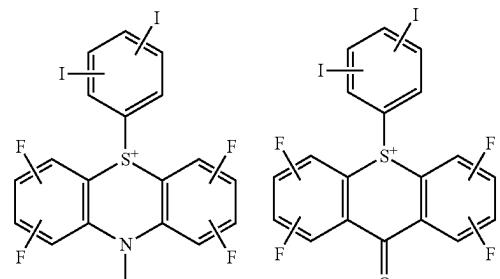
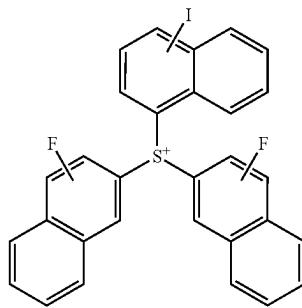
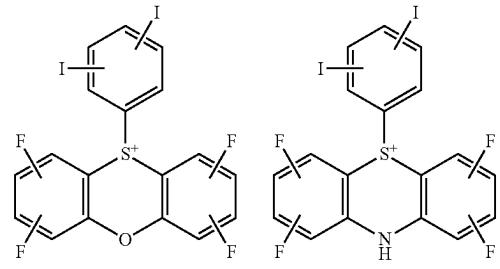
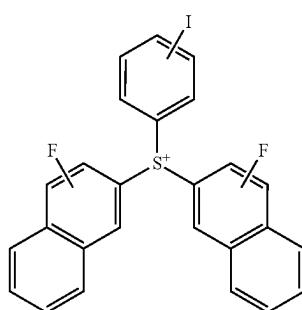
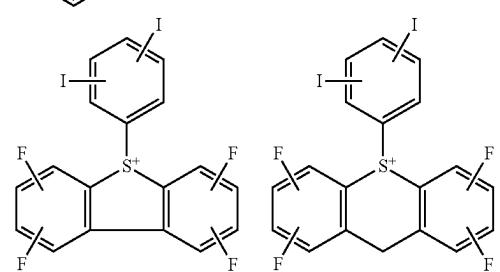
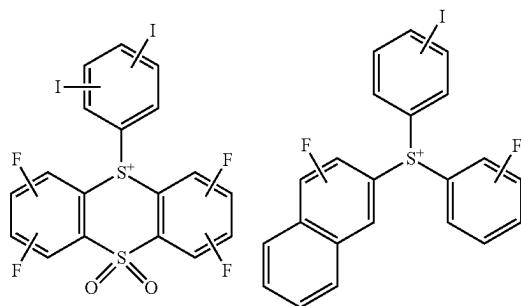
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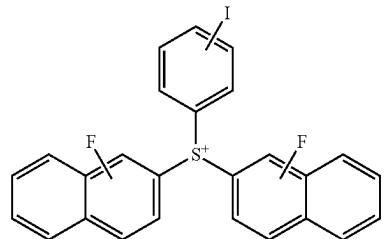
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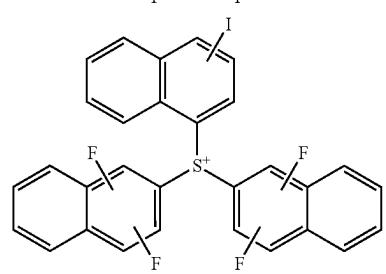
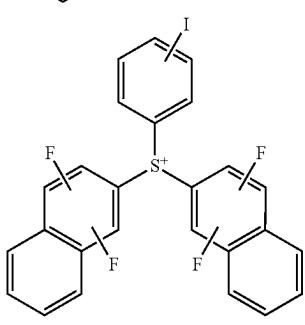
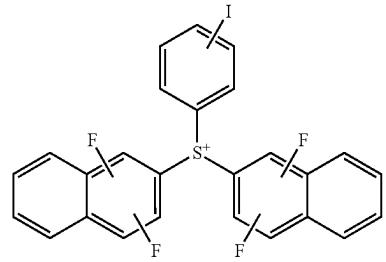
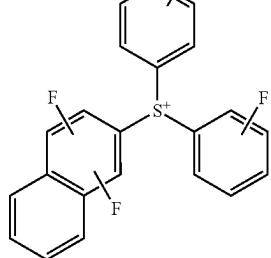
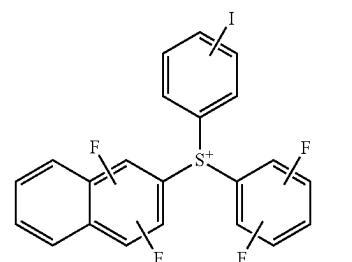
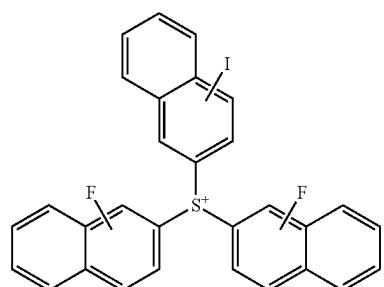
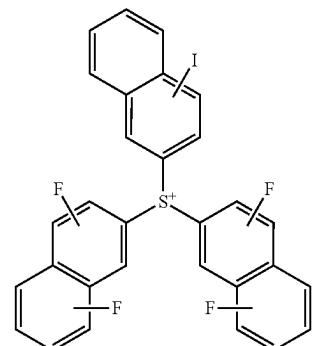
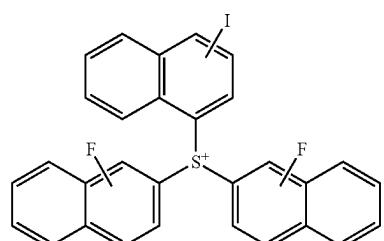
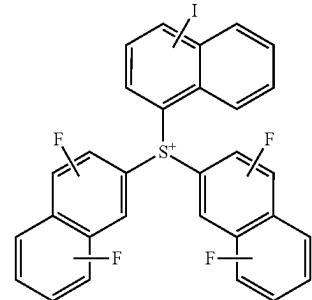
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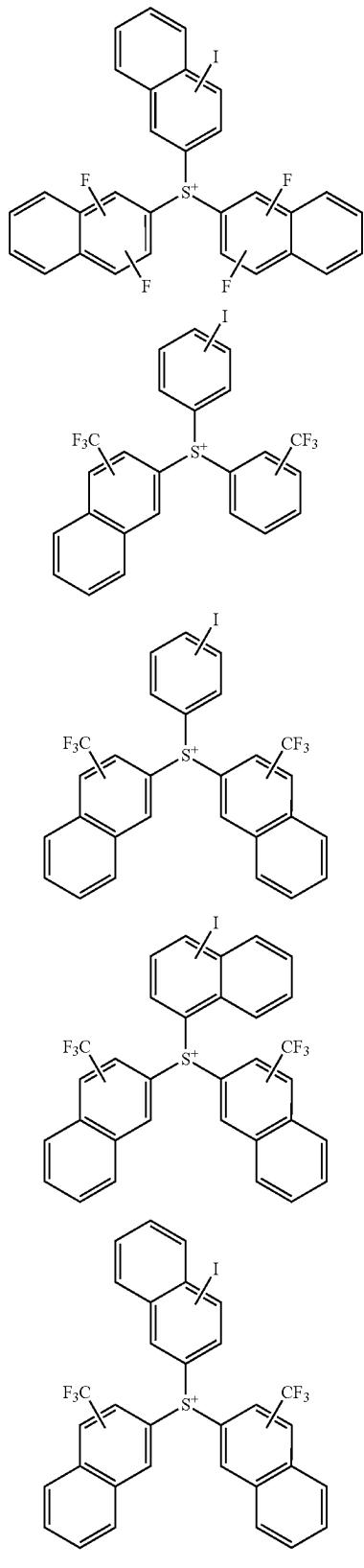
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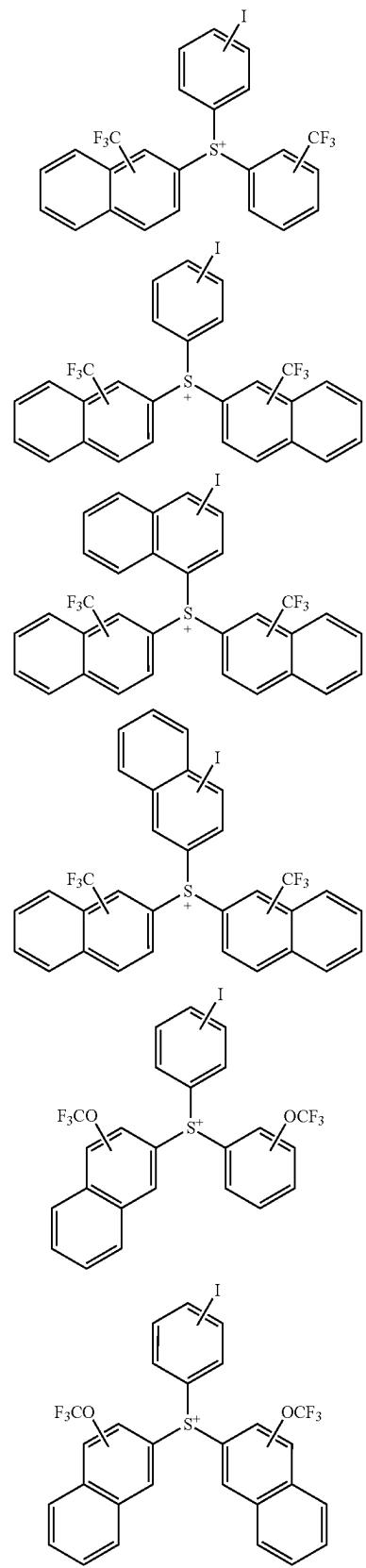
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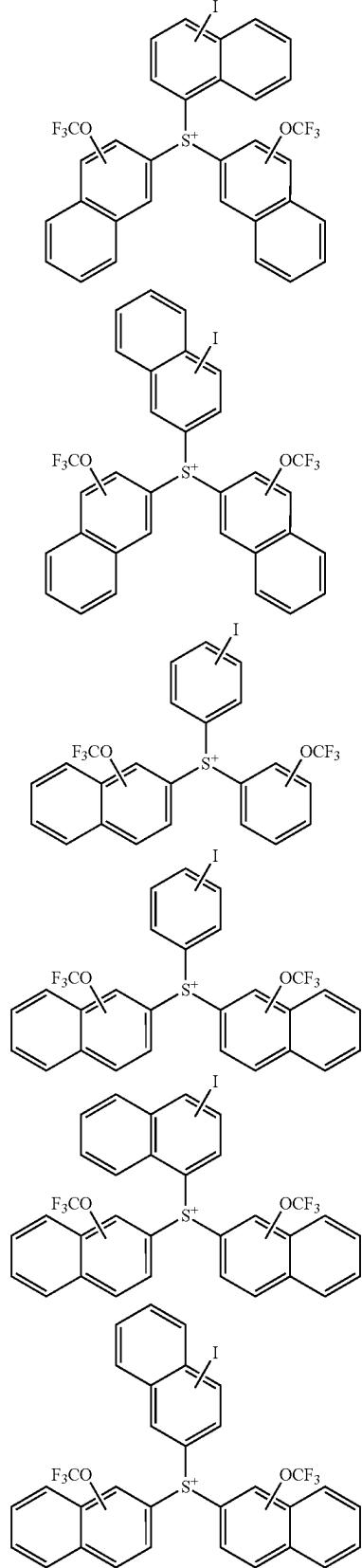
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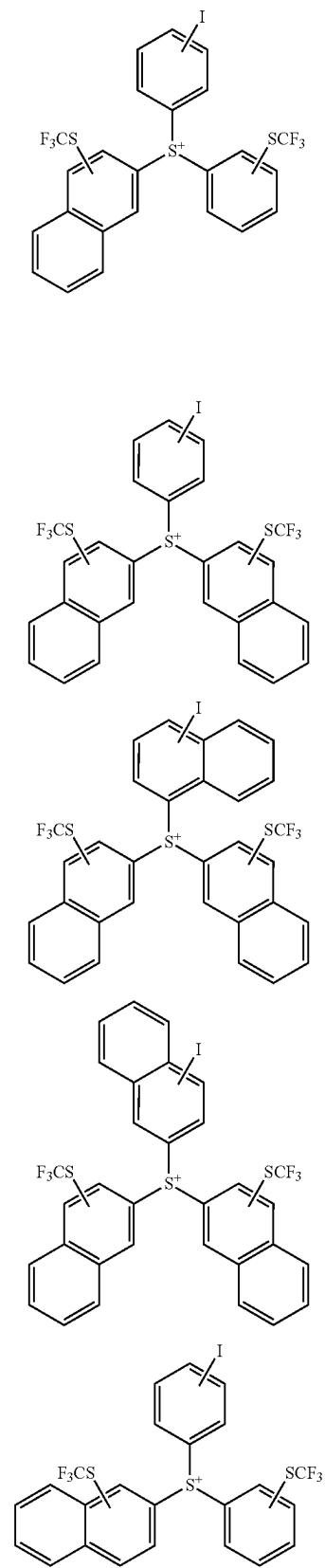
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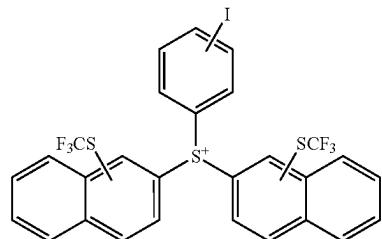
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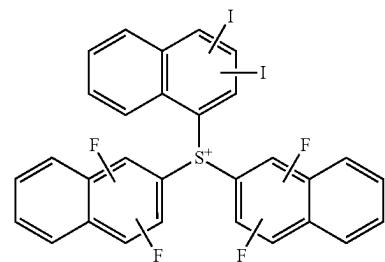
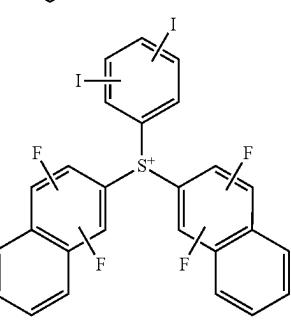
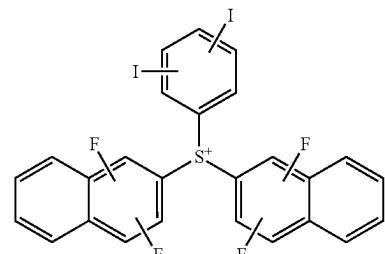
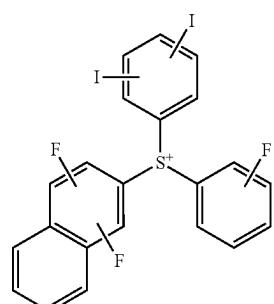
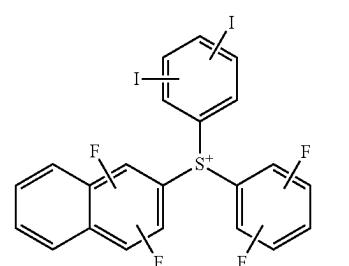
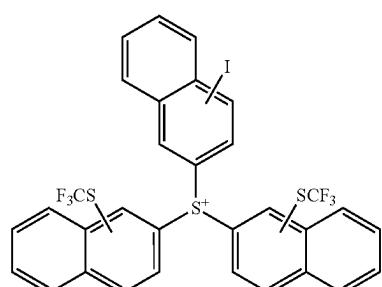
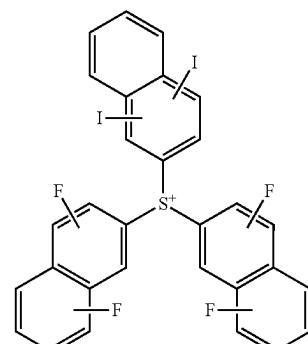
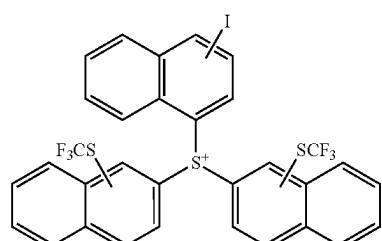
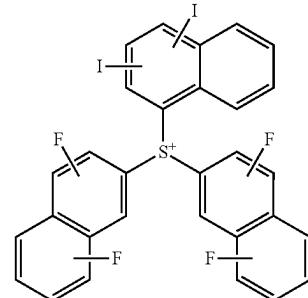
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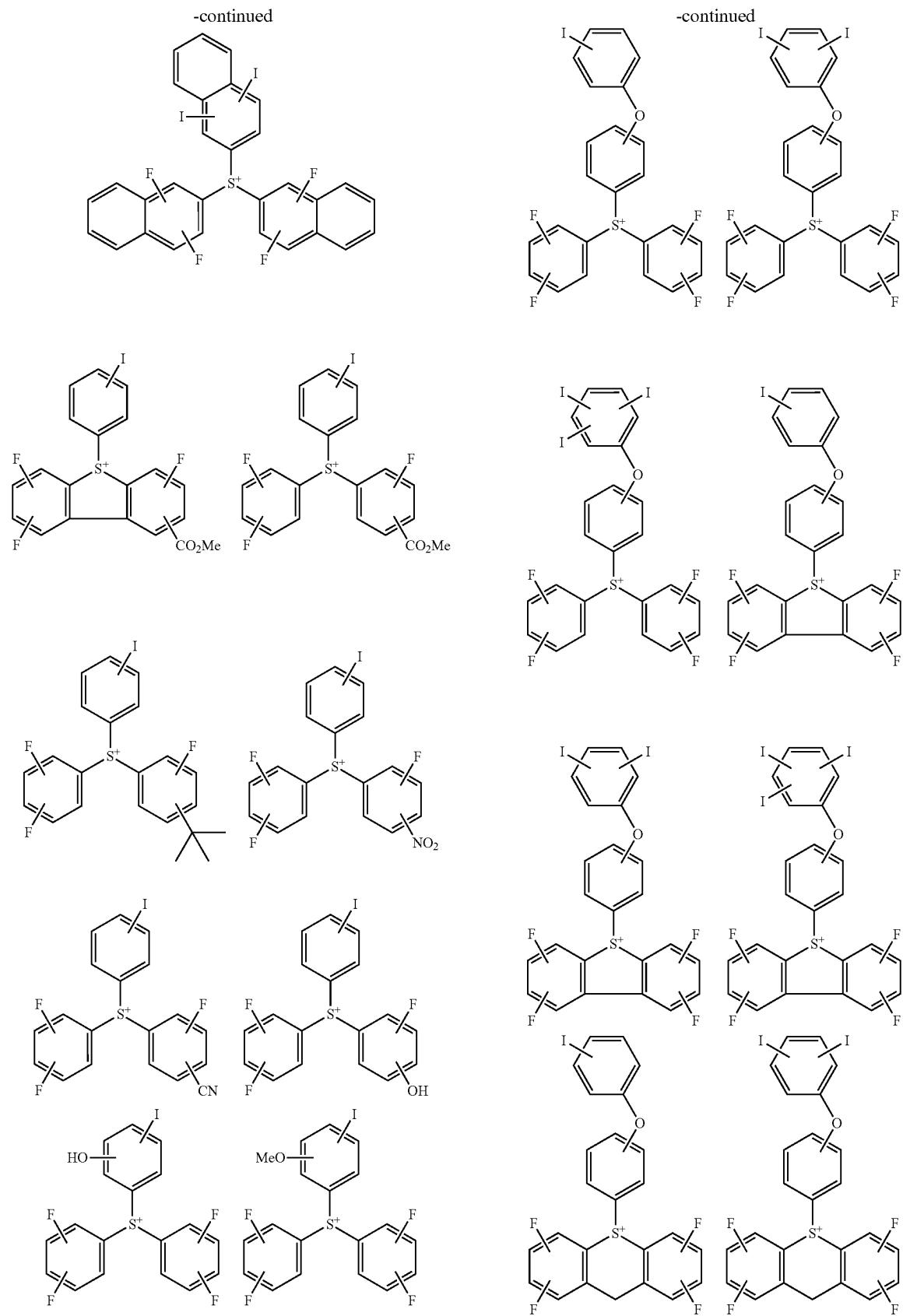


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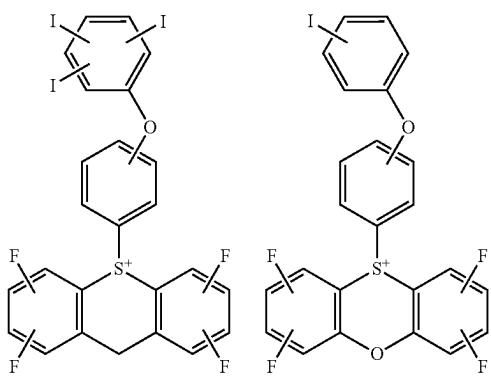


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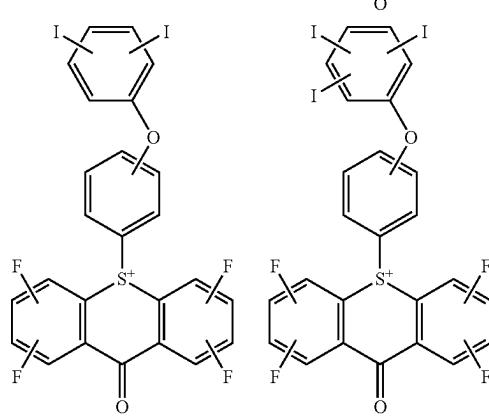
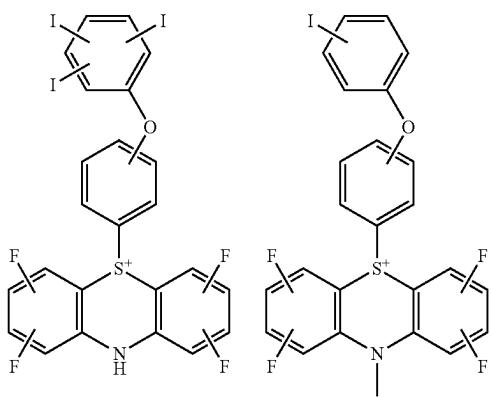
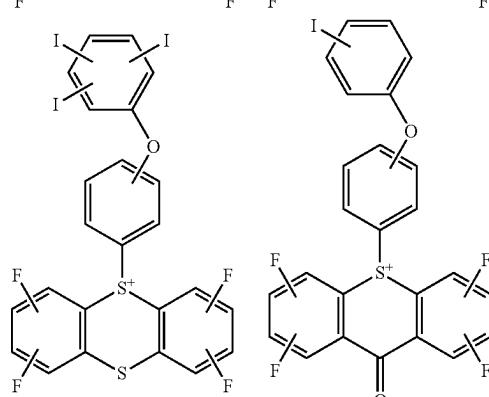
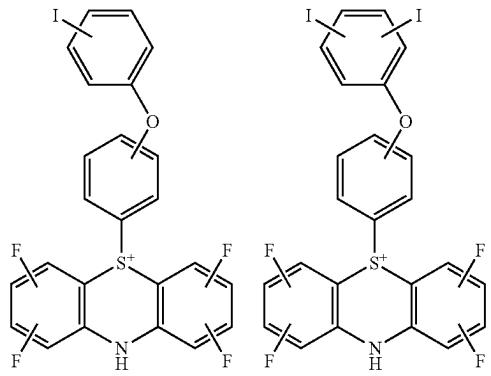
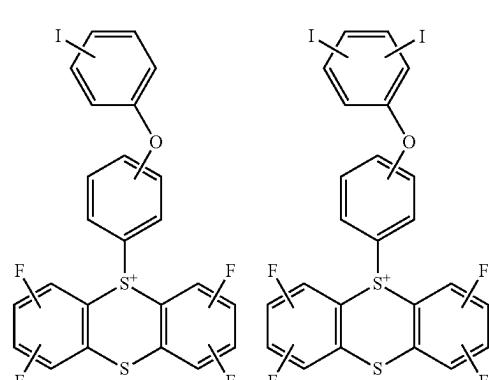
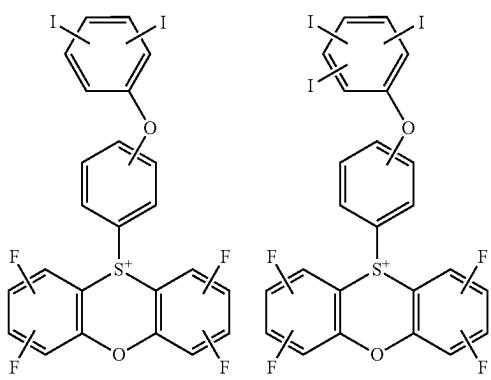
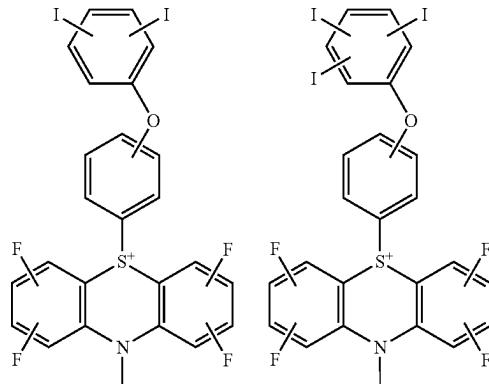




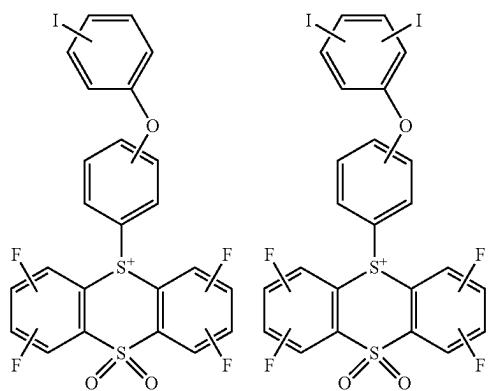
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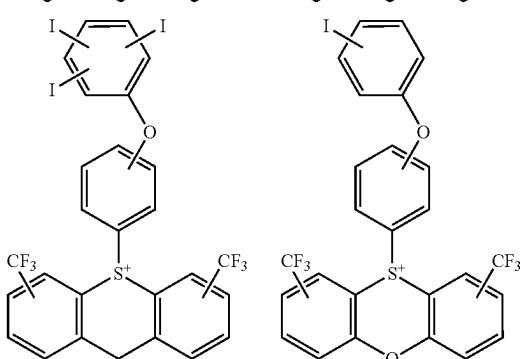
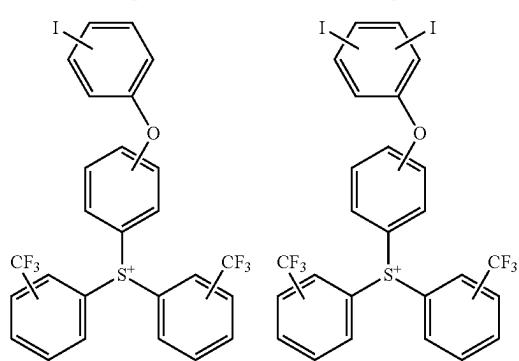
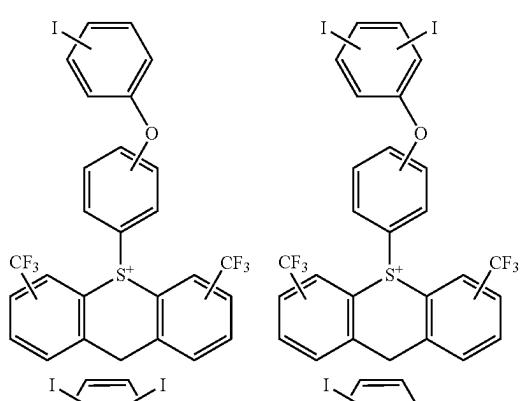
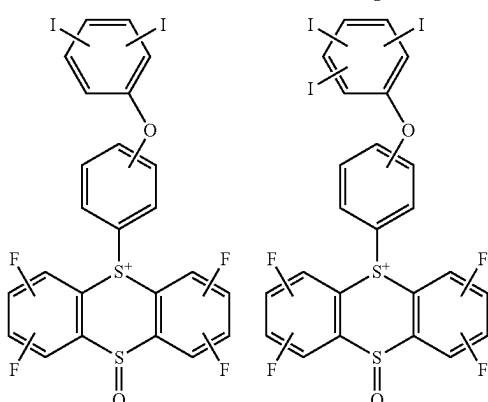
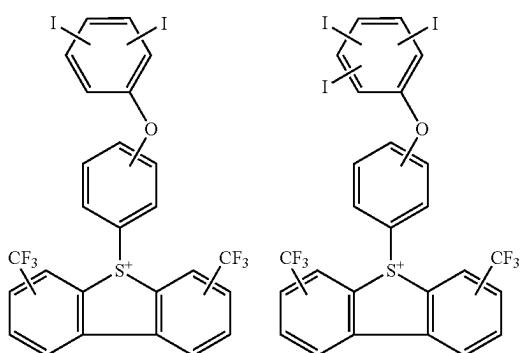
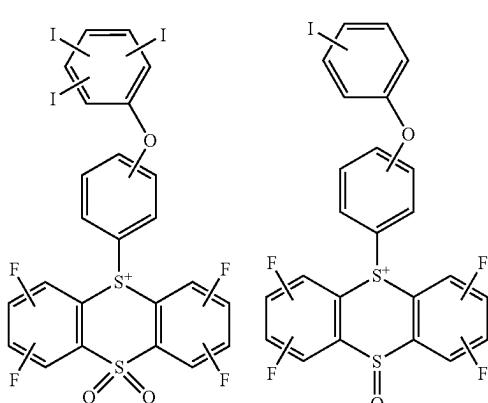
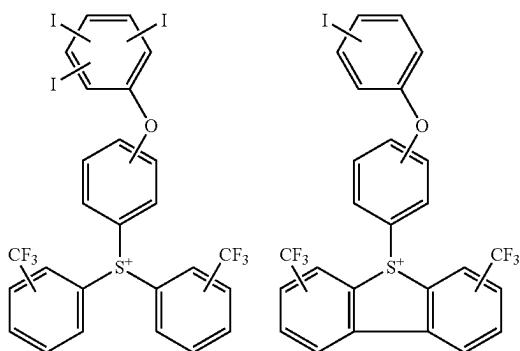
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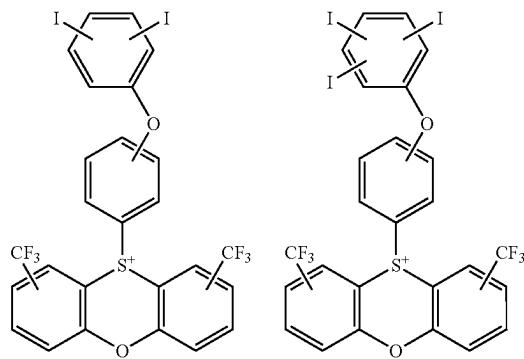
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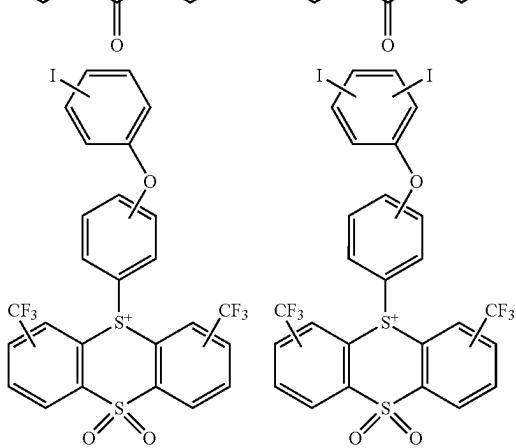
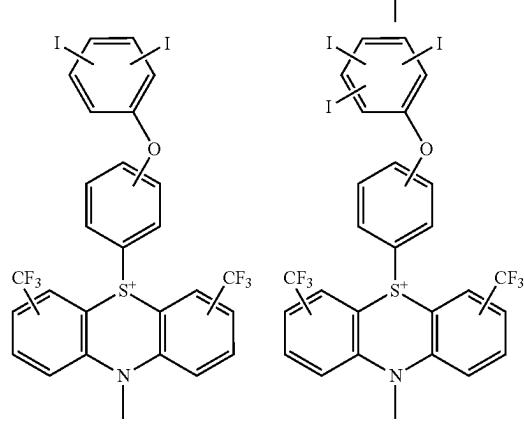
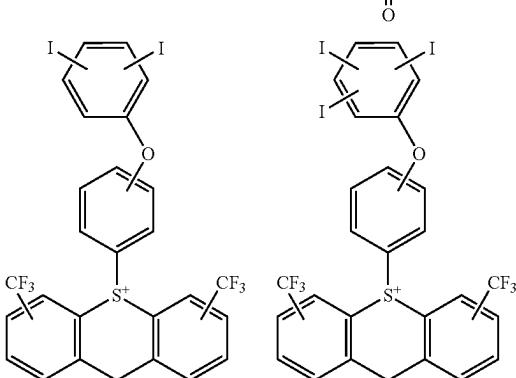
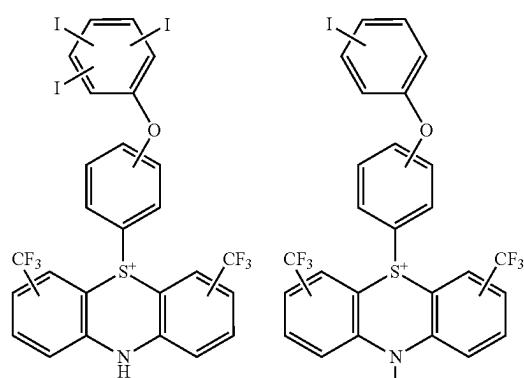
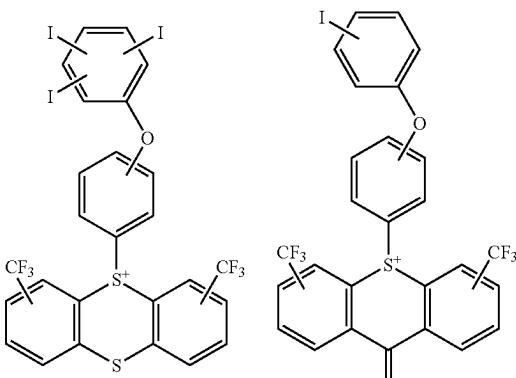
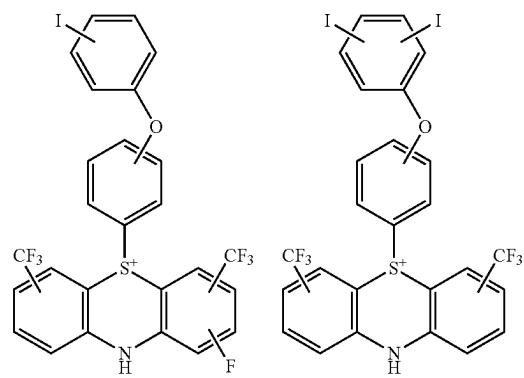
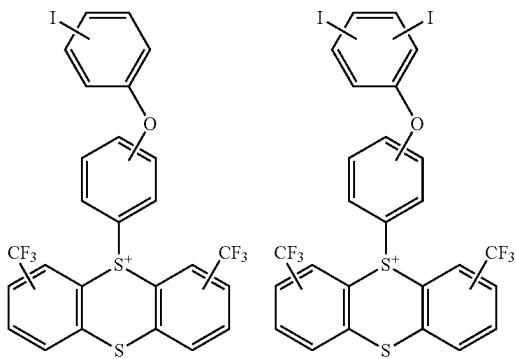
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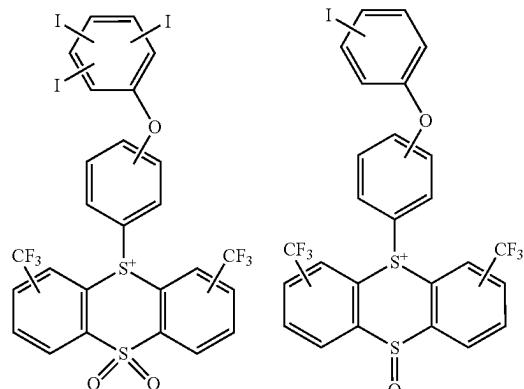
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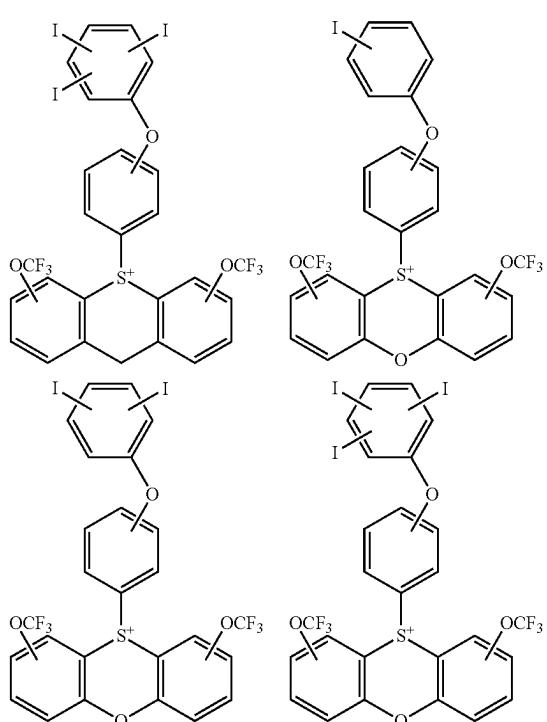
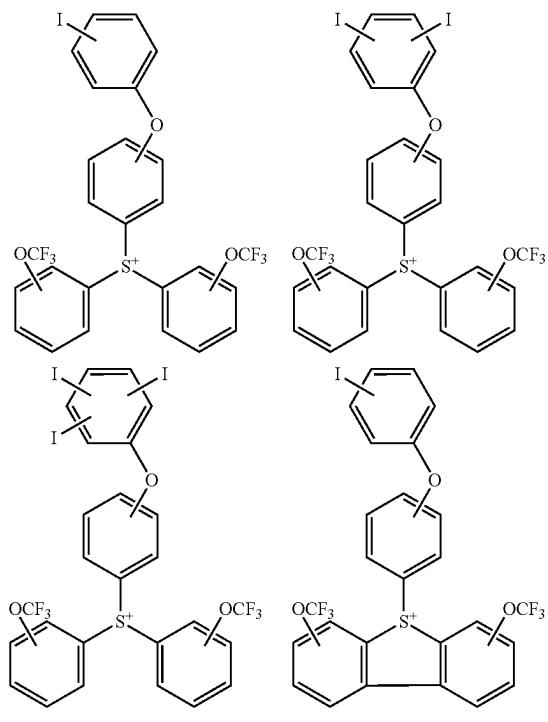
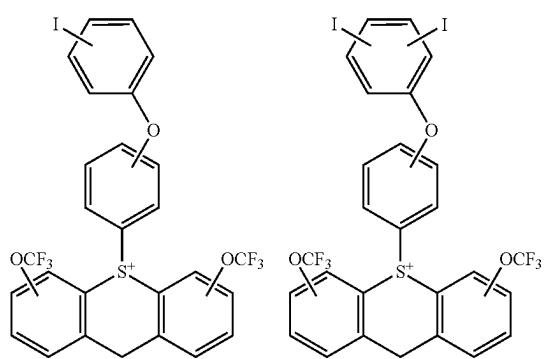
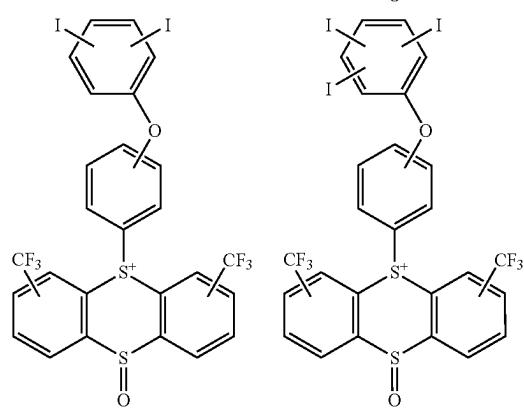
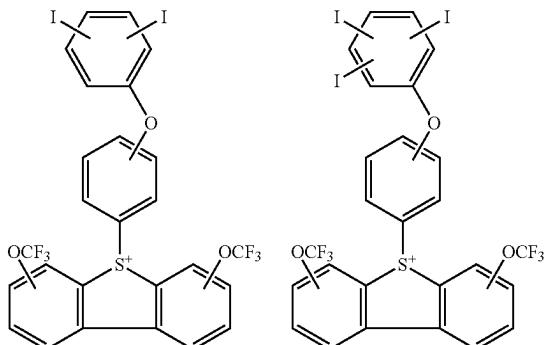
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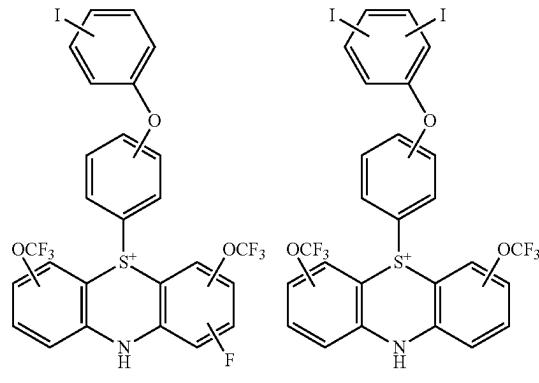
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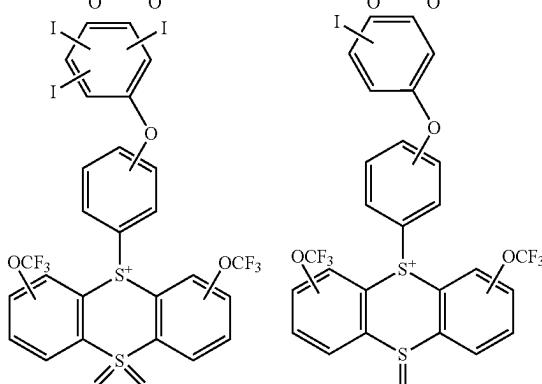
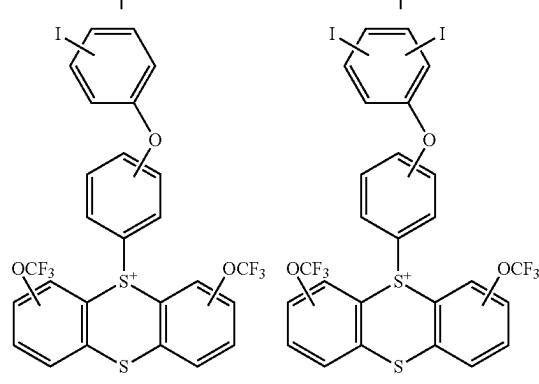
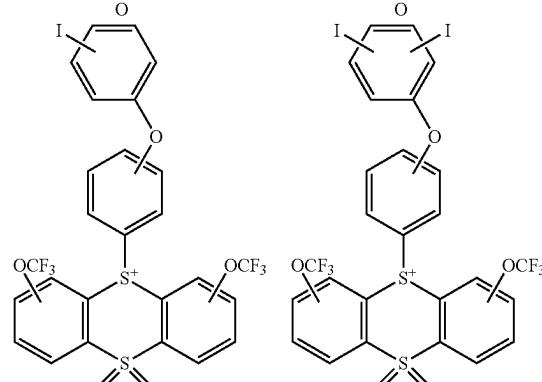
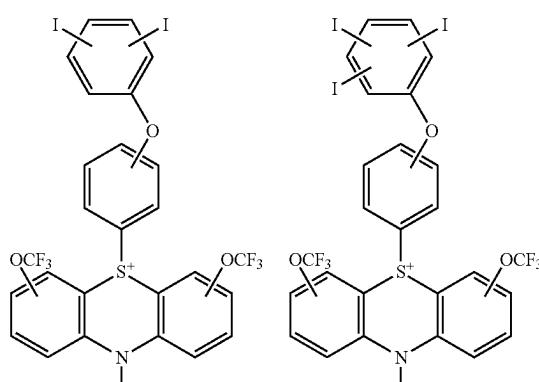
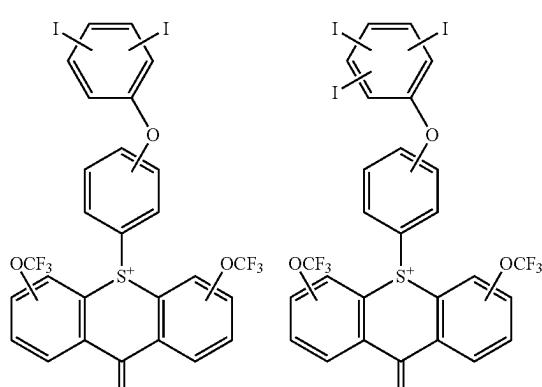
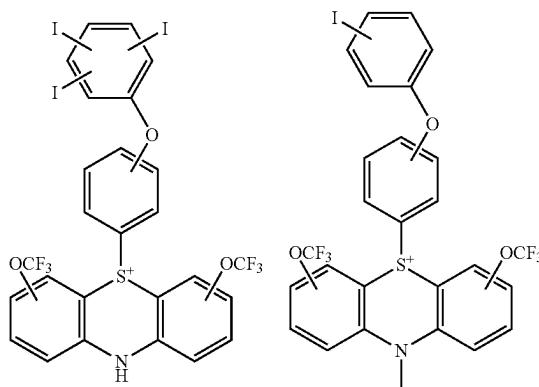
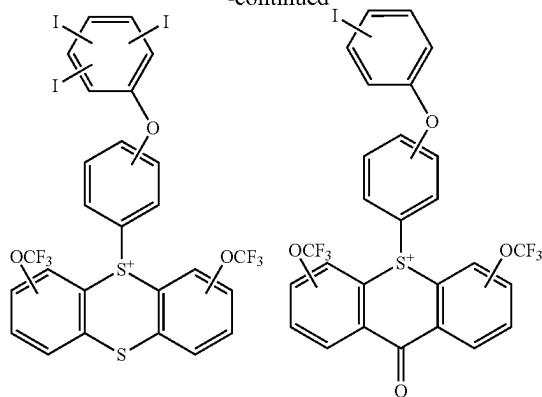
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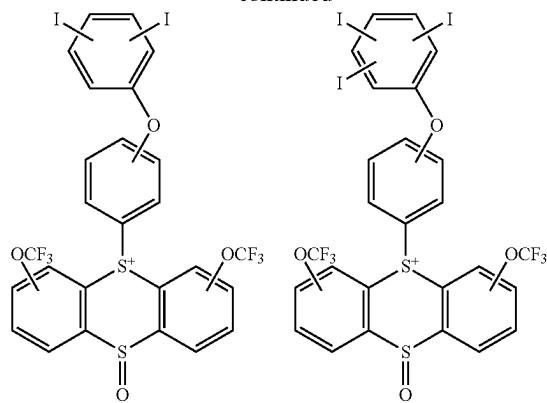
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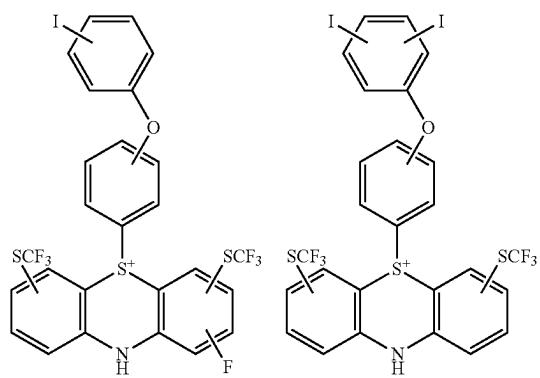
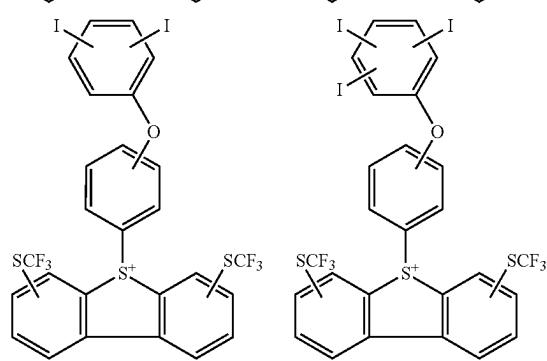
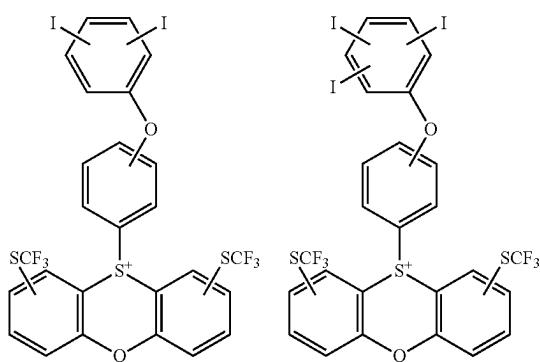
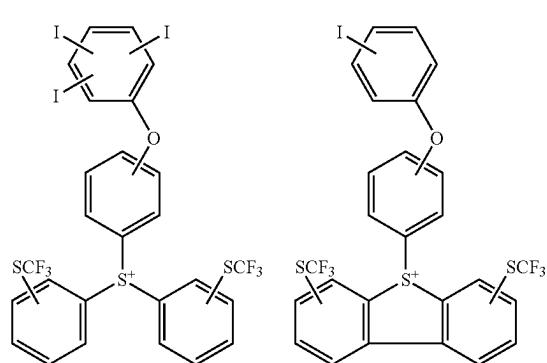
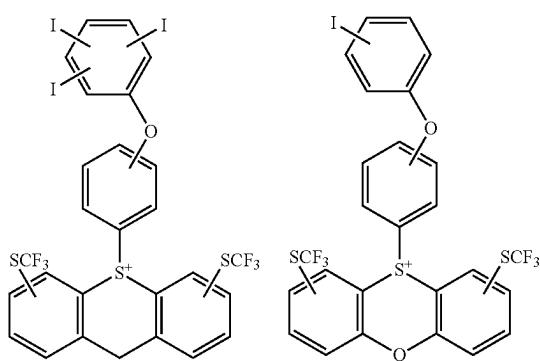
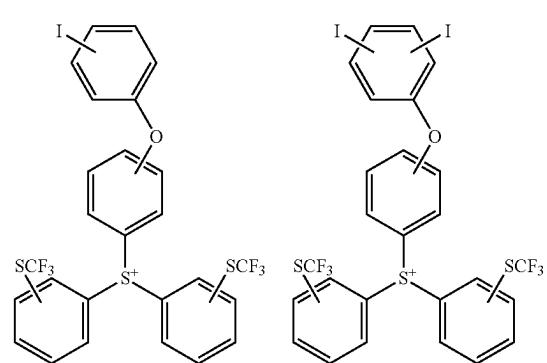
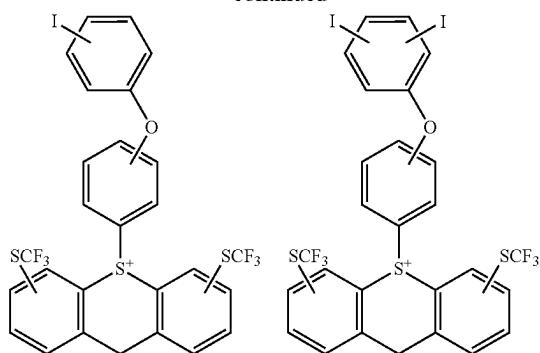
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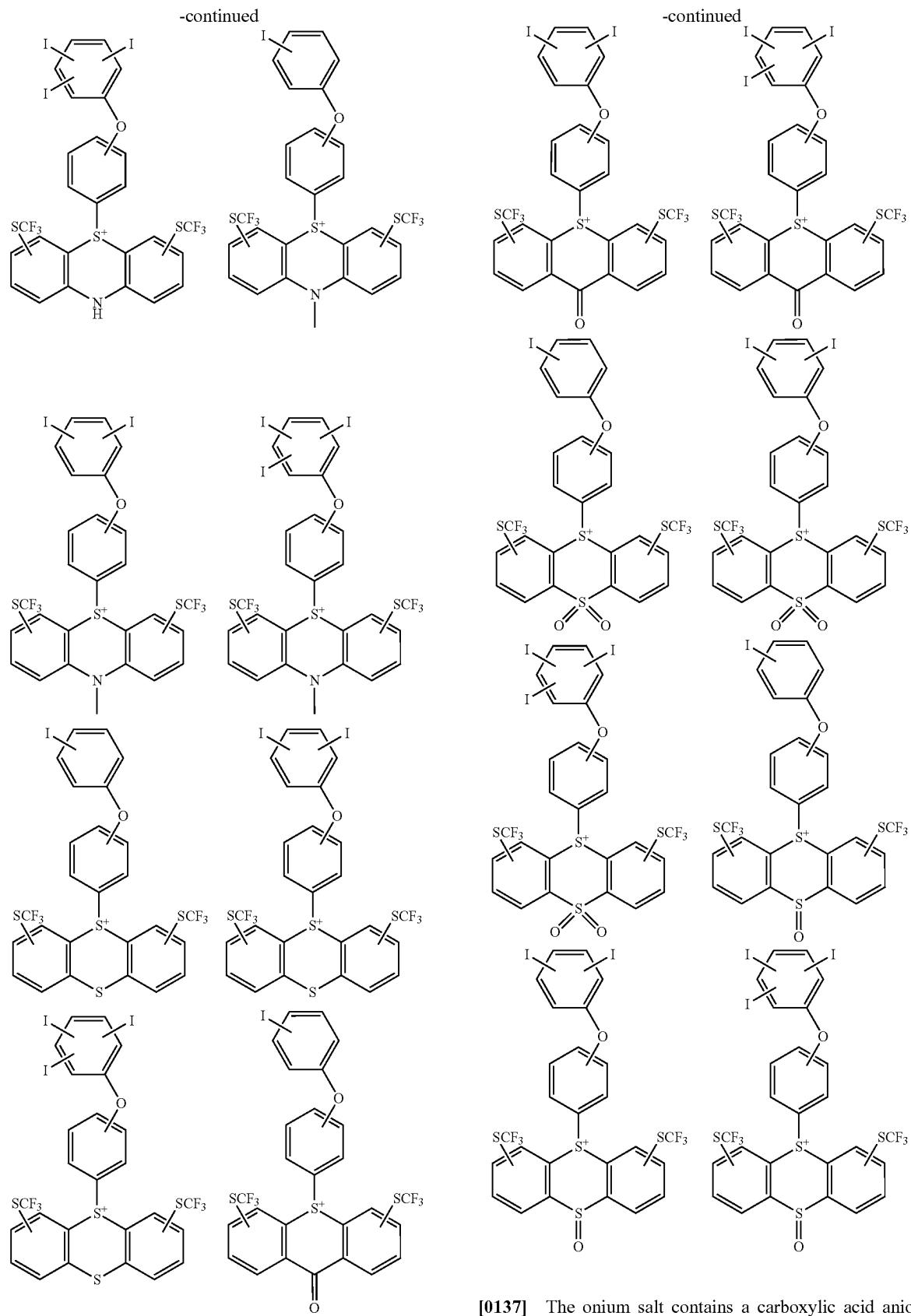


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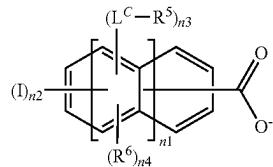


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[0137] The onium salt contains a carboxylic acid anion having the formula (1B).



(1B)

[0138] In formula (1B), n1 is 0 or 1. The relevant structure is a benzene ring in case of n1=0, and a naphthalene ring in case of n1=1. From the aspect of solvent solubility, the benzene ring corresponding to n1=0 is preferred. The subscript n2 is an integer of 1 to 4. From the aspect of availability of reactants, n2 is preferably 1, 2 or 3, and from the aspect of solvent solubility, n2 is more preferably 1 or 2. The subscript n3 is 1 or 2. The subscript n4 is an integer of 1 to 4. It is preferred from the aspect of availability of reactants that n4 be 0, 1, 2 or 3, more preferably 0, 1 or 2. These subscripts meet $2 \leq n_2 + n_3 + n_4 \leq 5$ in case of n1=0 and $2 \leq n_2 + n_3 + n_4 \leq 7$ in case of n1=1.

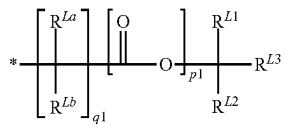
[0139] In formula (1B), L^C is a single bond, oxygen, sulfur, ester bond or carbonate bond. L^C is preferably oxygen when R^S is hydrogen. L^C is preferably oxygen, ester bond or carbonate bond, more preferably oxygen or ester bond when R^S is an acid labile group.

[0140] In formula (1B), when L^C is a single bond, R^S is hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom. The C₁-C₂₀ hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples of the hydrocarbyl group include C₁-C₂₀ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, tert-pentyl, n-hexyl, n-octyl, 2-ethylhexyl, n-nonyl, n-decyl, n-undecyl and n-dodecyl; C₃-C₂₀ cyclic saturated hydrocarbyl groups such as cyclopentyl, cyclohexyl, cyclopentylmethyl, cyclopentylethyl, cyclopentylbutyl, cyclohexylmethyl, cyclohexylethyl, cyclohexylbutyl, norbornyl, norbornylmethyl, adamantlyl, adamantlylmethyl, tricyclo[5.2.1.0^{2,6}]decyl, and tetracyclo[6.2.1.1^{3,6}.0^{2,7}]dodecyl; C₂-C₂₀ alkenyl groups such as vinyl, allyl, propenyl, butenyl, pentenyl and hexenyl; C₂-C₂₀ alkynyl groups such as ethynyl, propynyl, butynyl, pentynyl and hexynyl; C₃-C₂₀ cyclic unsaturated aliphatic hydrocarbyl groups such as cyclopentenyl and cyclohexenyl; C₆-C₂₀ aryl groups such as phenyl, naphthyl and indanyl; C₇-C₂₀ aralkyl groups such as benzyl, 1-phenylethyl and 2-phenylethyl, and combinations thereof. The hydrocarbyl group may contain a heteroatom such as halogen, oxygen or sulfur.

[0141] When L^C is oxygen, sulfur, ester bond or carbonate bond, R^S is hydrogen, a C₁-C₂₀ hydrocarbyl group (exclusive of acid labile group) which may contain a heteroatom, or acid labile group. Examples of the hydrocarbyl group are as exemplified above, with acid labile groups being excluded.

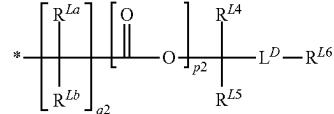
[0142] Typical of the acid labile group are groups having the following formulae (AL-1) and (AL-2).

(AL-1)



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(AL-2)



[0143] The asterisk (*) designates a point of attachment to the adjacent oxygen or sulfur.

[0144] In formulae (AL-1) and (AL-2), p1 and p2 are each independently 0 or 1, q1 and q2 are each independently an integer of 0 to 4. When L^C is oxygen with which R^S forms a carbonyl group, p1 or p2 is 1. Otherwise, p1 or p2 is preferably 0. When p1=1, q1 is preferably 1 or 2, and when p1=0, q1 is 0. When p2=1, q2 is preferably 1 or 2, and when p2=0, q2 is 0.

[0145] In formula (AL-1), R^{L1}, R^{L2} and R^{L3} are each independently a C₁-C₁₂ hydrocarbyl group in which some —CH₂— may be replaced by —O— or —S—. When the hydrocarbyl group contains an aromatic ring, some or all of the hydrogen atoms in the aromatic ring may be substituted by halogen, cyano moiety, nitro moiety, optionally halogenated C₁-C₄ alkyl moiety, or optionally halogenated C₁-C₄ alkoxy moiety.

[0146] The C₁-C₁₂ hydrocarbyl group represented by R^{L1}, R^{L2} and R^{L3} may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C₁-C₁₂ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, tert-pentyl, n-hexyl, n-octyl, 2-ethylhexyl, n-nonyl, n-decyl, n-undecyl, and n-dodecyl; C₃-C₁₂ cyclic saturated hydrocarbyl groups such as cyclopentyl, cyclohexyl, cyclopentylmethyl, cyclopentylethyl, cyclopentylbutyl, cyclohexylmethyl, cyclohexylethyl, cyclohexylbutyl, norbornyl, norbornylmethyl, adamantlyl, adamantlylmethyl, tricyclo[5.2.1.0^{2,6}]decyl, and tetracyclo[6.2.1.1^{3,6}.0^{2,7}]dodecyl; C₂-C₁₂ alkenyl groups such as vinyl, allyl, propenyl, butenyl, pentenyl, and hexenyl; C₂-C₁₂ alkynyl groups such as ethynyl, propynyl, butynyl, pentynyl and hexynyl; C₃-C₁₂ cyclic unsaturated aliphatic hydrocarbyl groups such as cyclopentenyl and cyclohexenyl; C₆-C₂₀ aryl groups such as phenyl, naphthyl and indanyl; C₇-C₁₂ aralkyl groups such as benzyl, 1-phenylethyl, and 2-phenylethyl, and combinations thereof.

[0147] R^{L1} and R^{L2} may bond together to form a ring with the carbon atom to which they are attached, and some —CH₂— in the ring may be replaced by —O— or —S—. Exemplary rings include cyclopropane, cyclobutane, cyclopentane, cyclohexane, cycloheptane, cyclooctane, norbornane, adamantanane, tricyclo[5.2.1.0^{2,6}]decane, and tetracyclo[6.2.1.1^{3,6}.0^{2,7}]dodecane rings as well as these rings in which some —CH₂— is replaced by —O— or —S—.

[0148] In formula (AL-2), RN and R^{L5} are each independently hydrogen or a C₁-C₁₀ hydrocarbyl group. The hydrocarbyl group represented by RN and R^{L5} may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include those exemplified above for the hydrocarbyl group represented by R^{L1}, R^{L2} and R^{L3}, but of 1 to 10 carbon atoms.

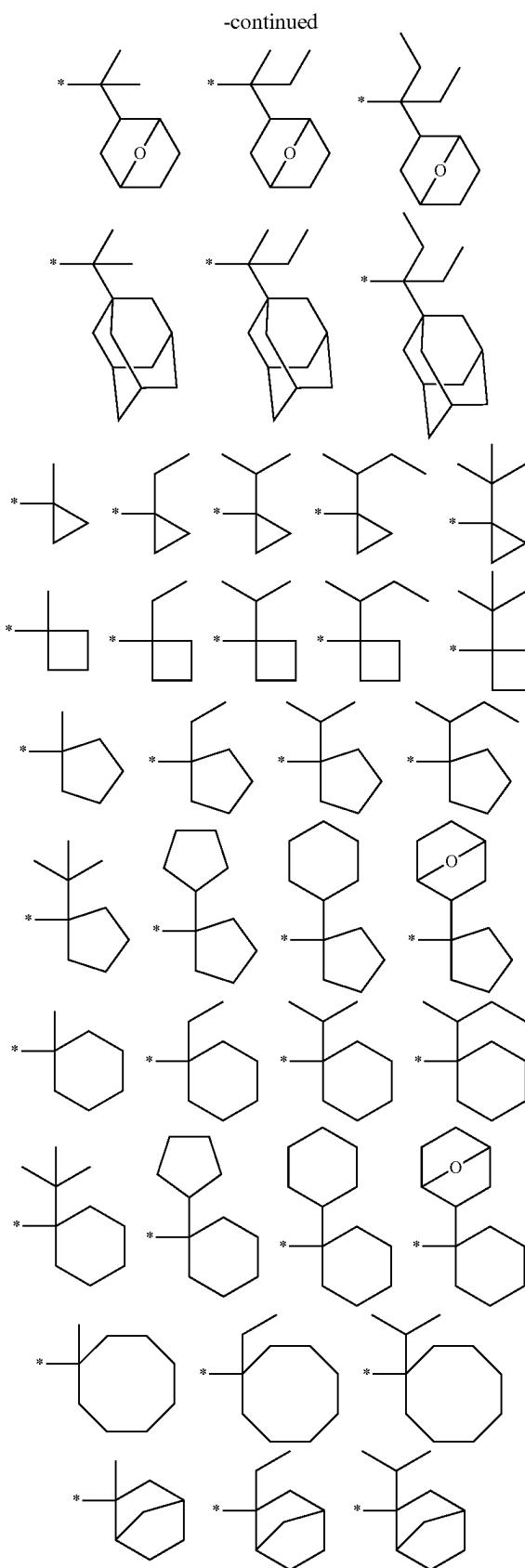
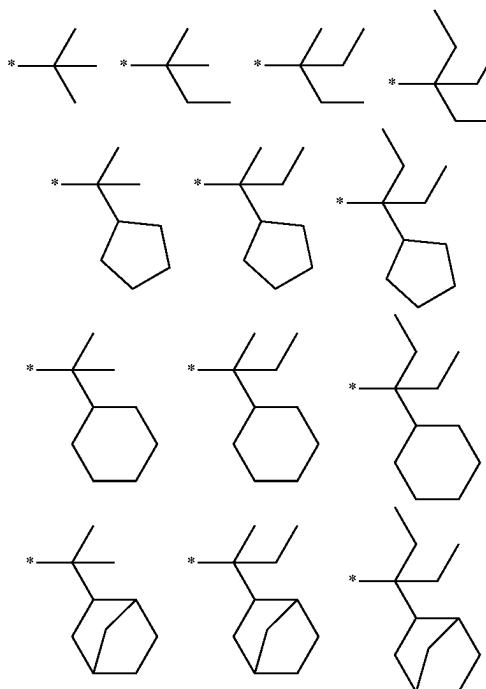
[0149] In formula (AL-2), R^{L6} is a C₁-C₂₀ hydrocarbyl group in which some —CH₂— may be replaced by —O— or —S—. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C₁-C₂₀ alkyl groups such as methyl, ethyl,

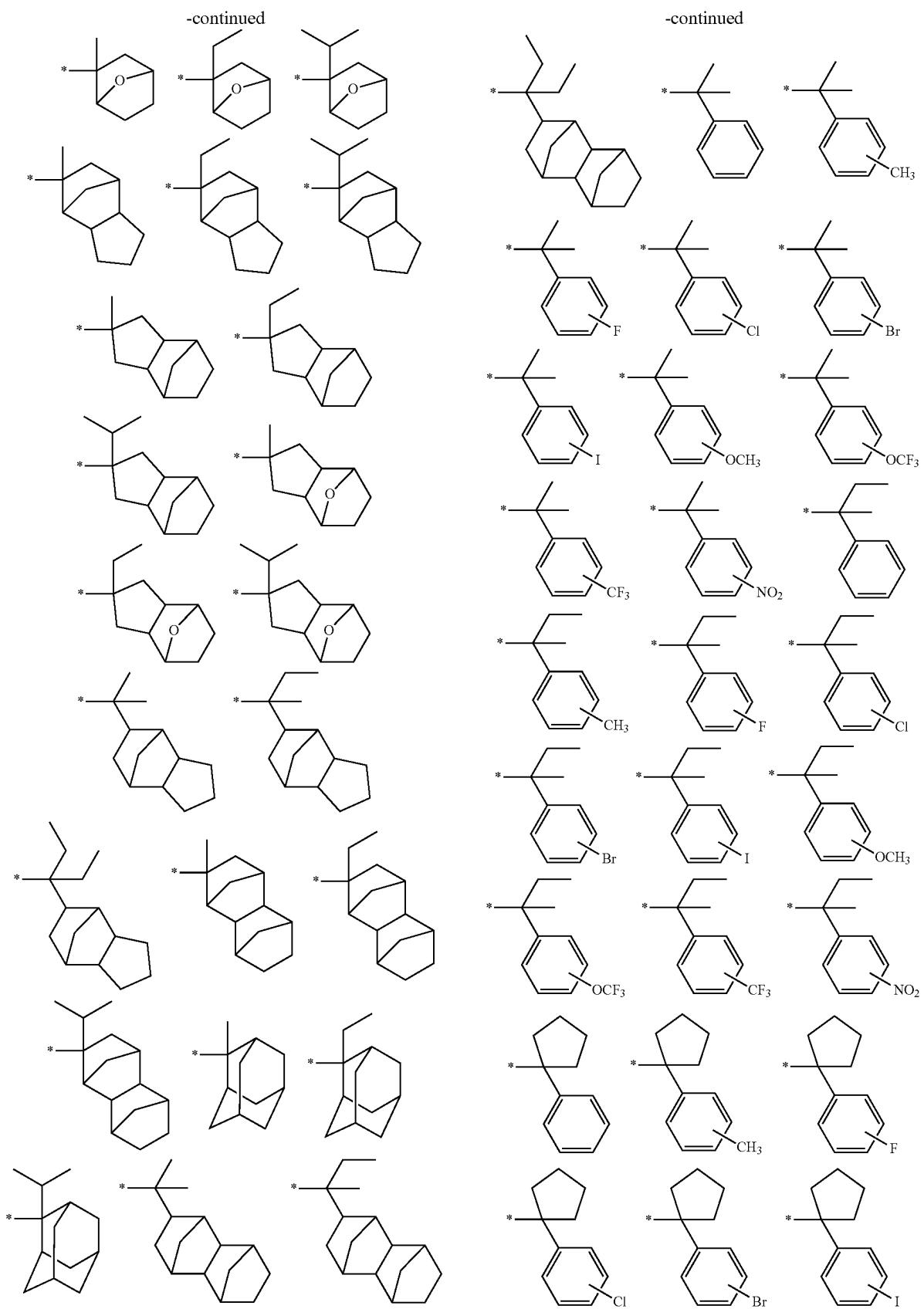
n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, n-hexyl, n-octyl, n-nonyl, n-decyl, undecyl, dodecyl, tridecyl, tetradecyl, pentadecyl, heptadecyl, octadecyl, nonadecyl and icosyl; C₃-C₂₀ cyclic saturated hydrocarbyl groups such as cyclopropyl, cyclopentyl, cyclohexyl, cyclopropylmethyl, 4-methylcyclohexyl, cyclohexylmethyl, norbornyl, norbornylmethyl, adamantlyl, adamantlylmethyl, tricyclo[5.2.1.0^{2,6}]decyl, and tetracyclo[6.2.1.1^{3,6}.0^{2,7}]dodecyl; C₂-C₂₀ alkenyl groups such as vinyl, propenyl, butenyl, pentenyl and hexenyl; C₂-C₂₀ alkynyl groups such as ethynyl, propynyl, butynyl, pentynyl and hexynyl; C₃-C₂₀ cyclic unsaturated aliphatic hydrocarbyl groups such as cyclopentenyl, cyclohexenyl and norbornenyl; C₆-C₂₀ aryl groups such as phenyl, methylphenyl, ethylphenyl, n-propylphenyl, isopropylphenyl, n-butylphenyl, isobutylphenyl, sec-butylphenyl, tert-butylphenyl, naphthyl, methylnaphthyl, ethylnaphthyl, n-propynaphthyl, isopropylnaphthyl, n-butynaphthyl, isobutynaphthyl, sec-butynaphthyl, and tert-butynaphthyl; C₇-C₂₀ aralkyl groups such as benzyl and phenethyl, and combinations thereof. Also, R^{L5} and R^{L6} may bond together to form a C₃-C₂₀ heterocyclic group with the carbon atom and L^D to which they are attached, and some —CH₂— in the heterocyclic group may be replaced by —O— or —S—.

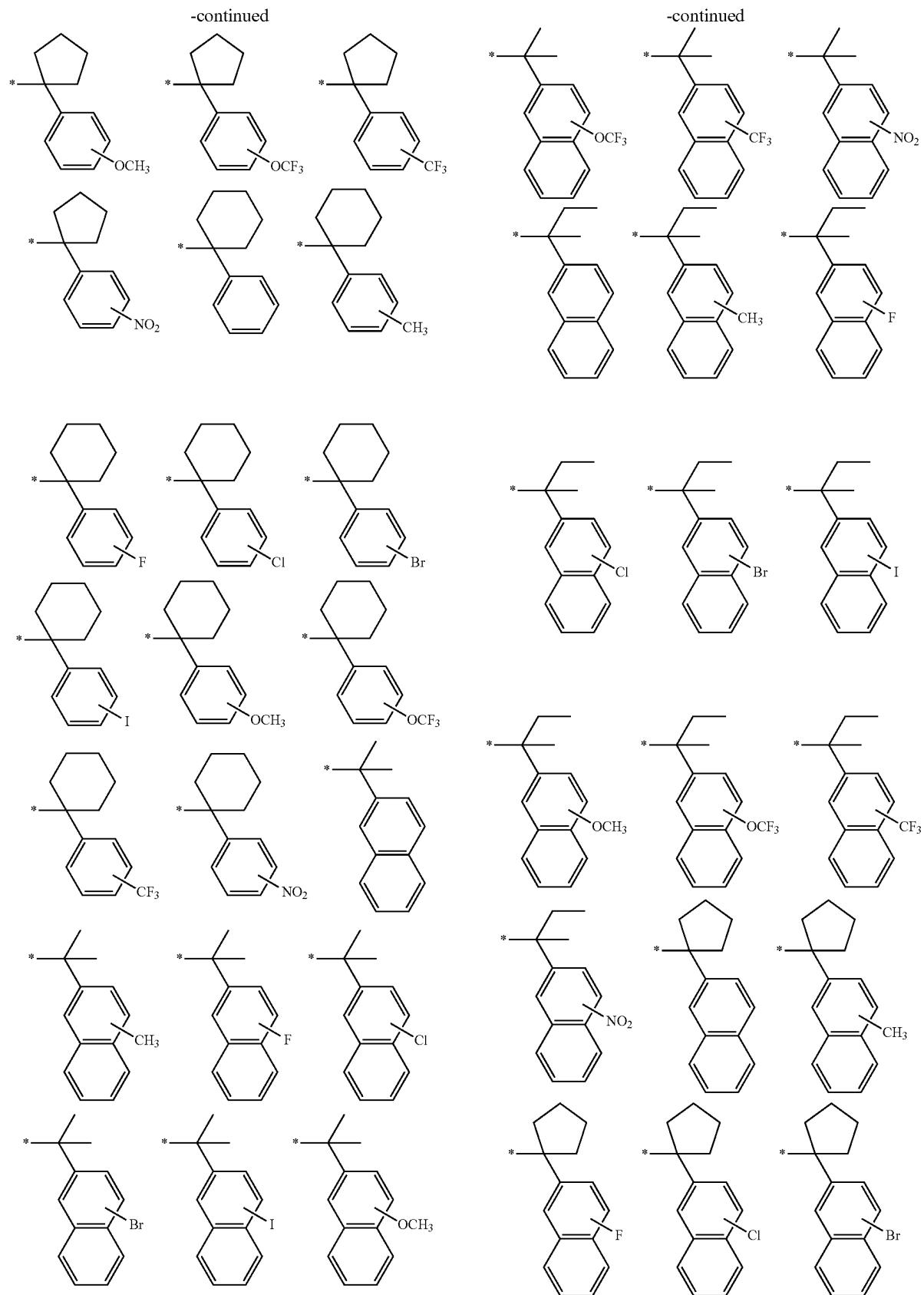
[0150] In formula (AL-2), L^D is —O— or —S—.

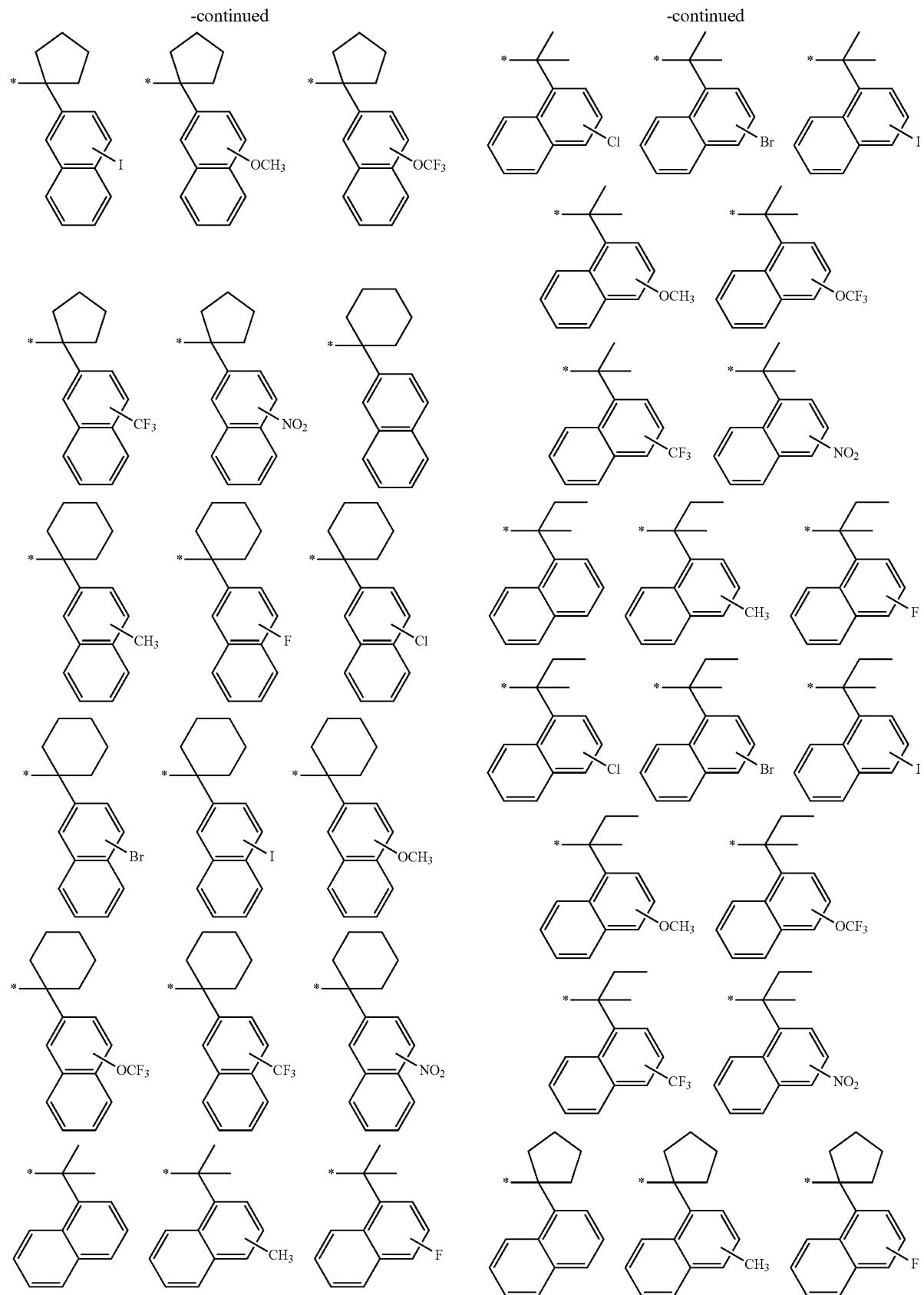
[0151] In formulae (AL-1) and (AL-2), R^{L1a} to R^{L6d} are each independently hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include those exemplified above for the hydrocarbyl group R⁵, but are not limited thereto.

[0152] Examples of the acid labile group having formula (AL-1) are shown below, but not limited thereto. Herein * designates a point of attachment to the adjacent oxygen or sulfur.

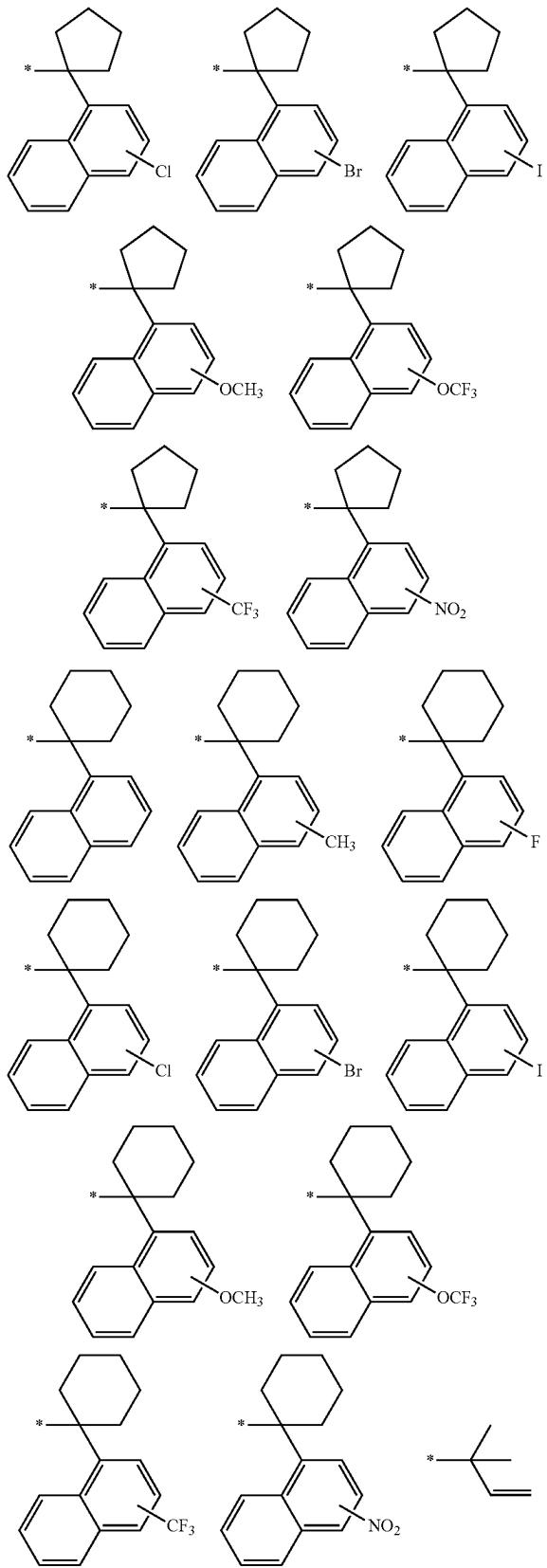




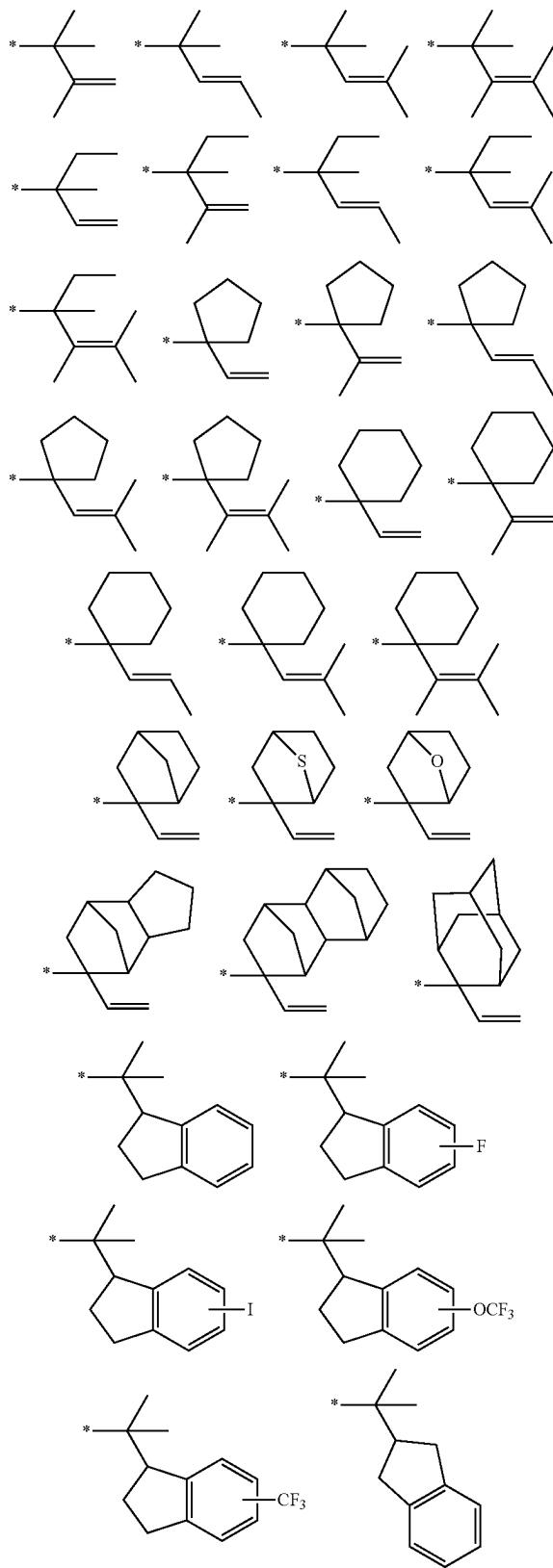


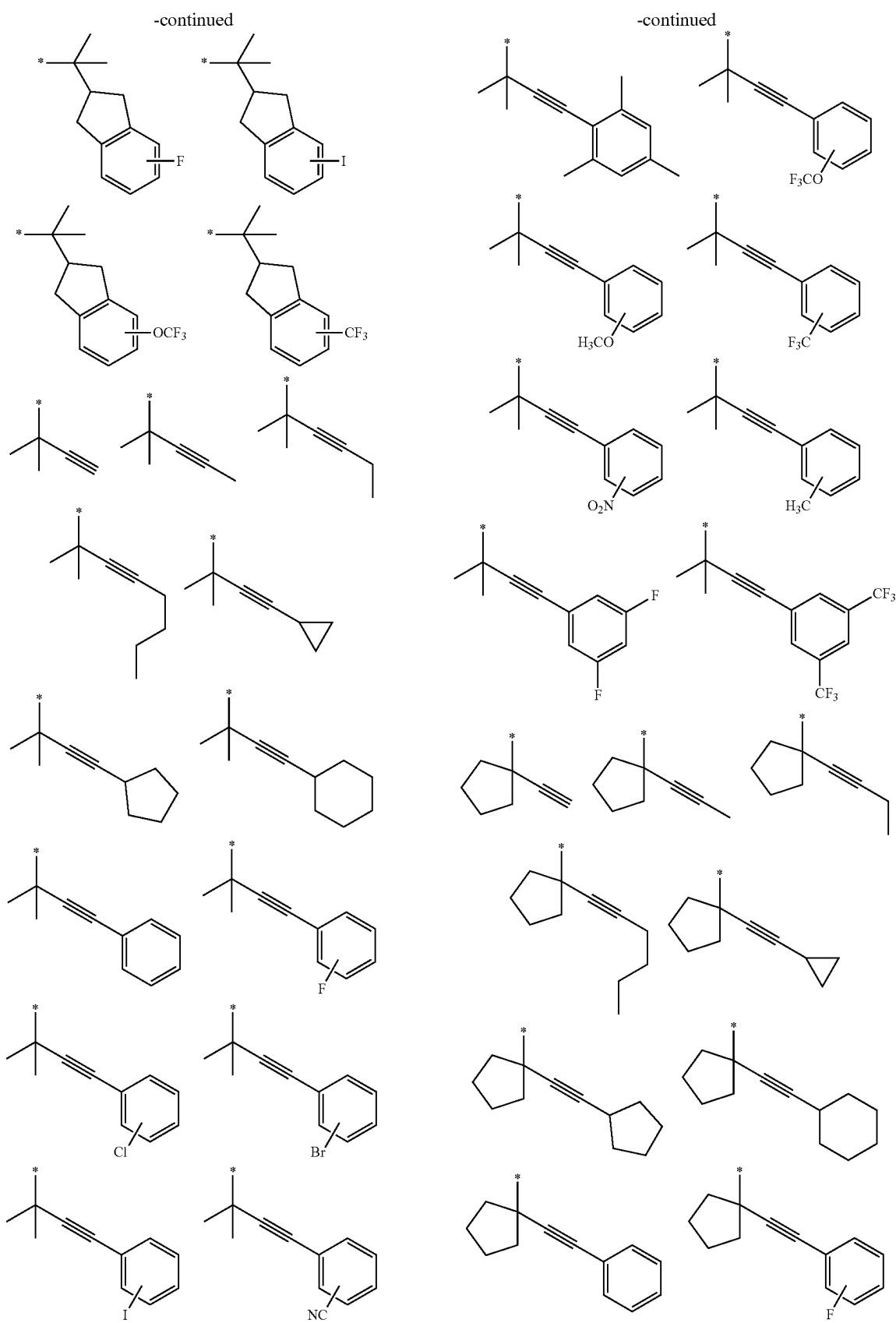


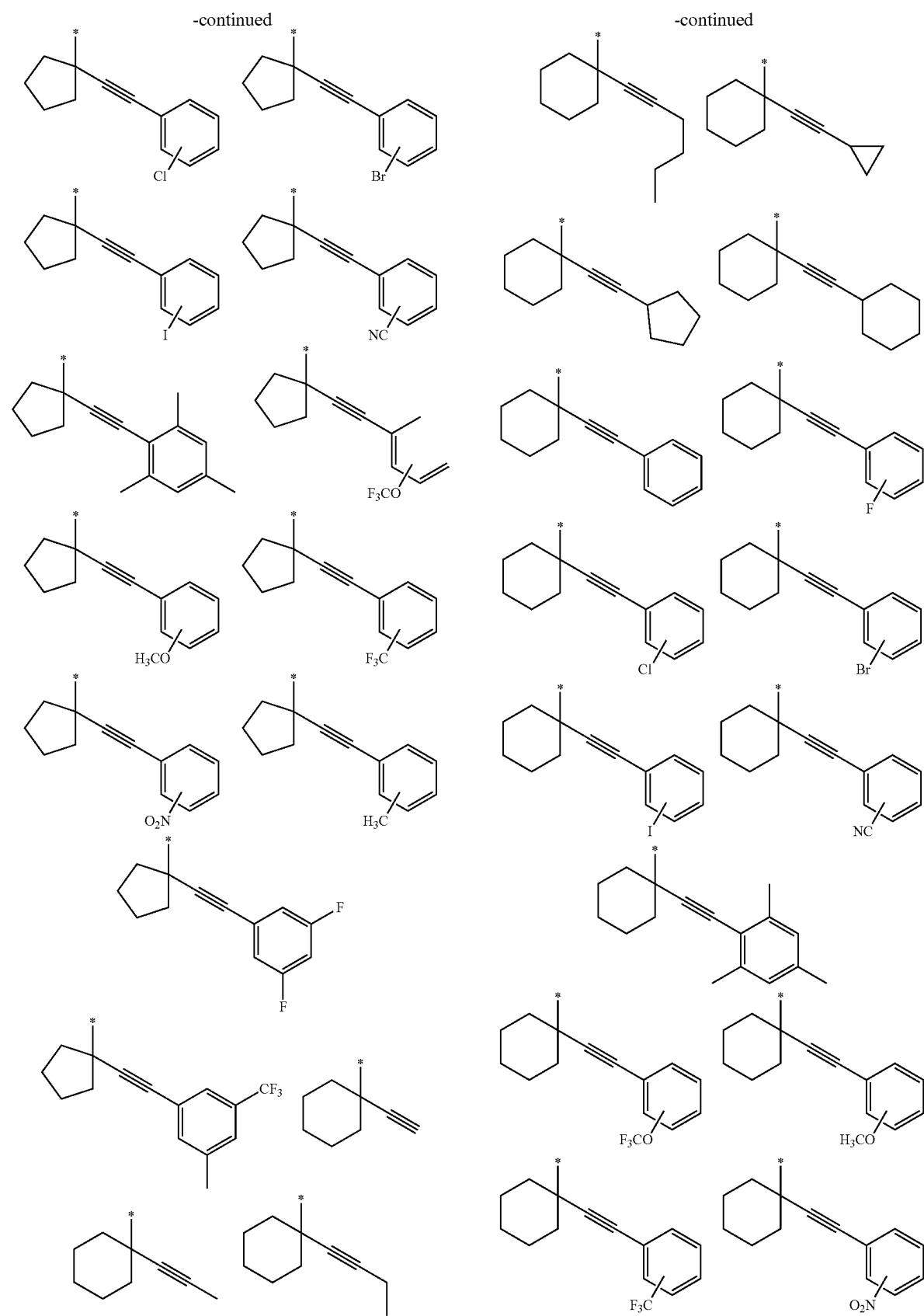
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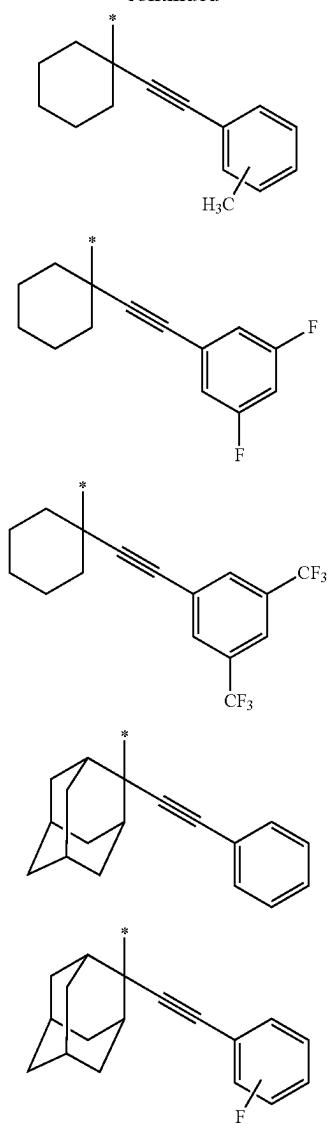
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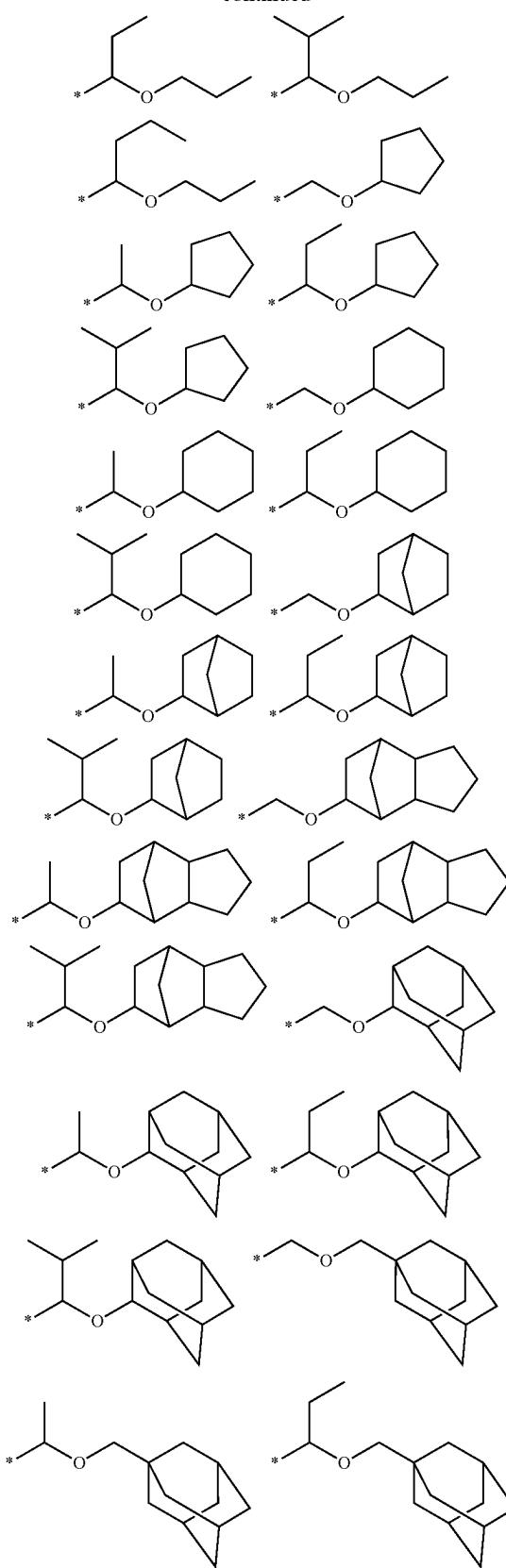




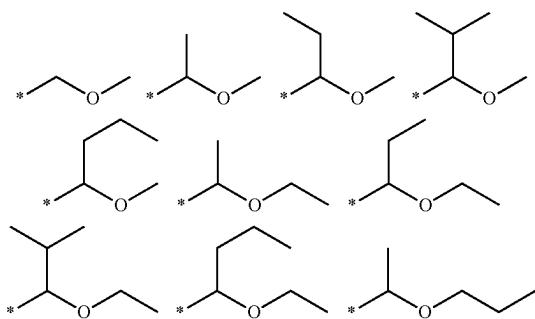
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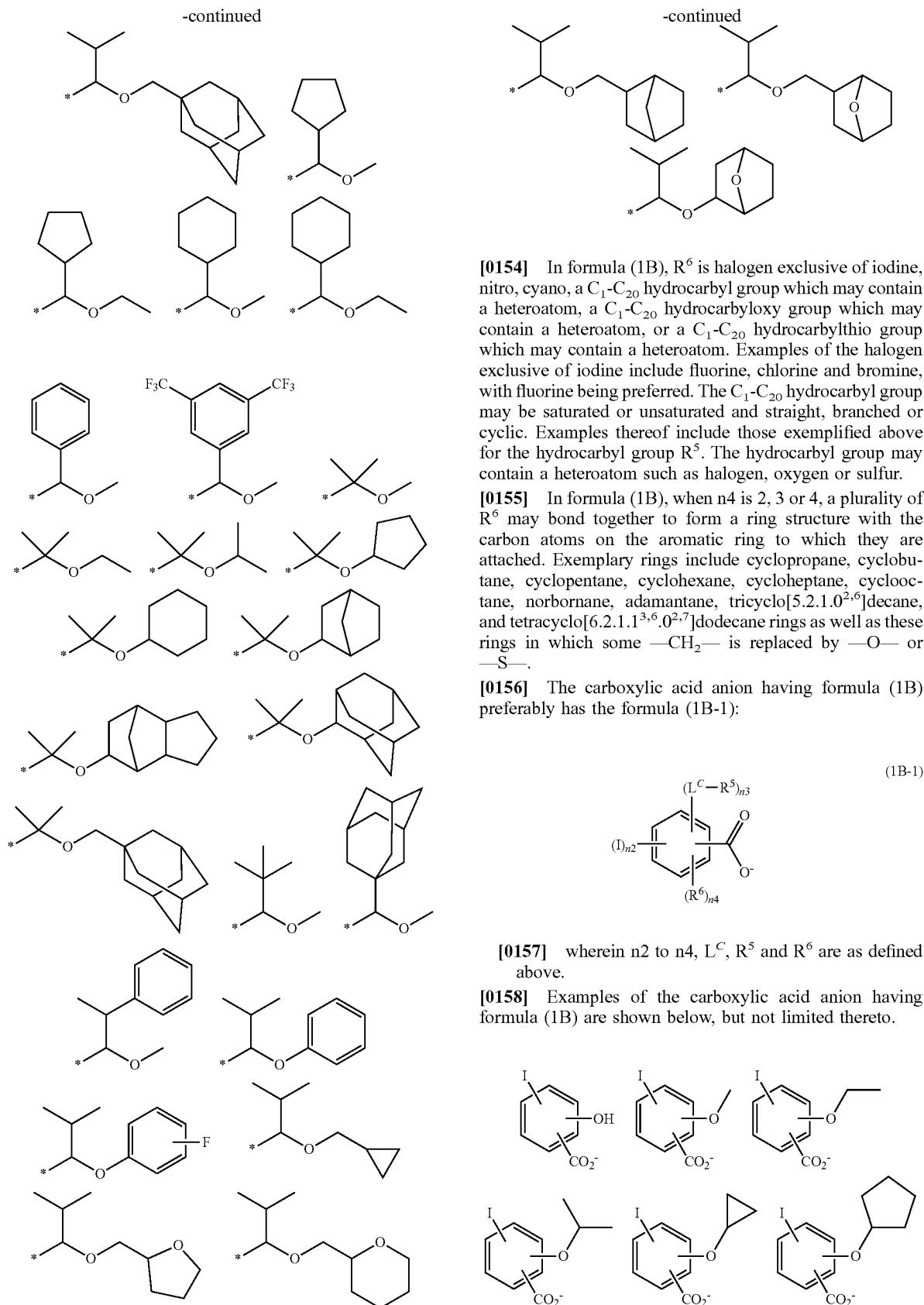


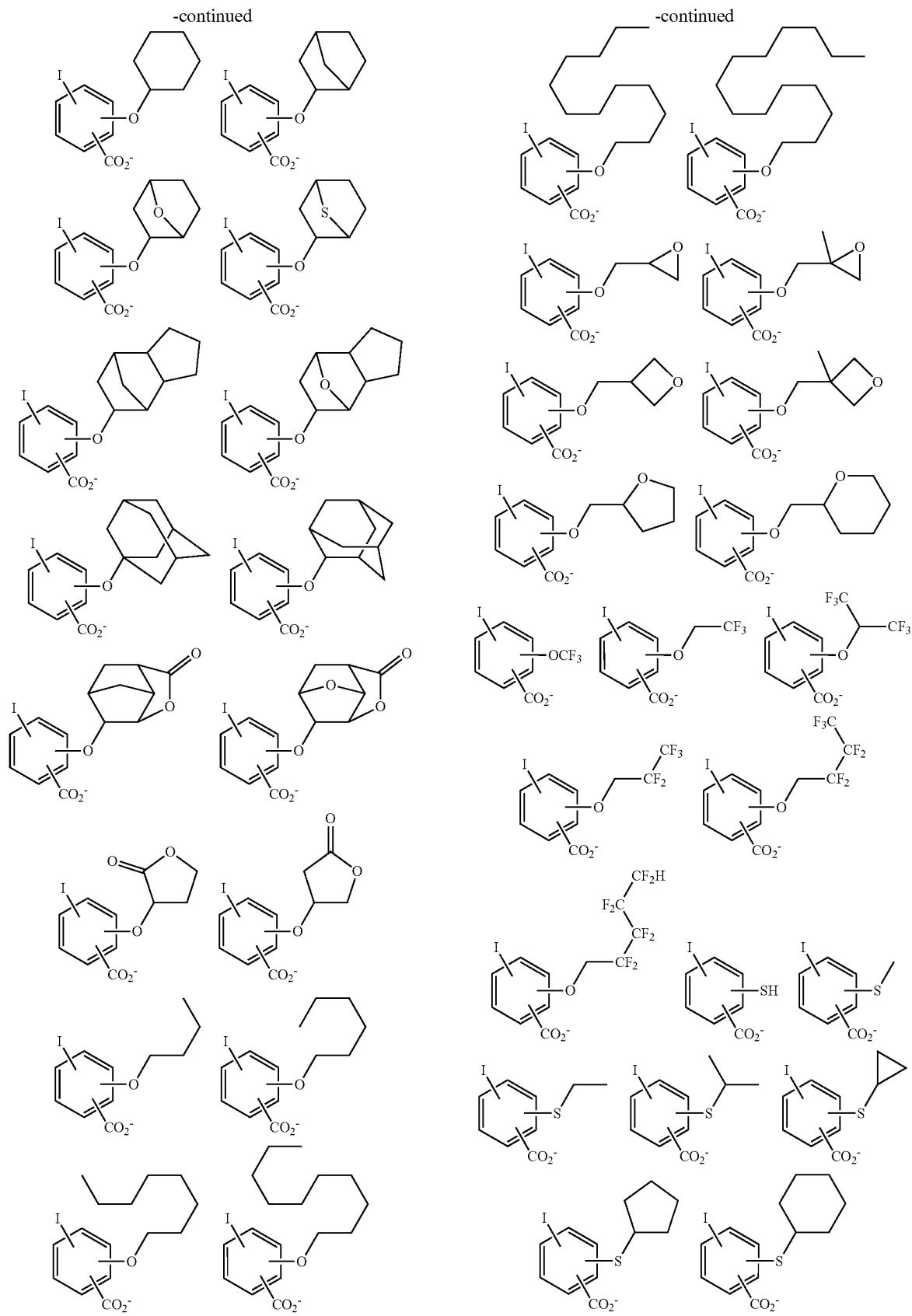
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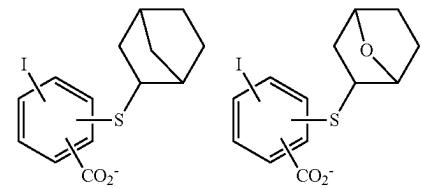
[0153] Examples of the acid labile group having formula (AL-2) are shown below, but not limited thereto. Herein * designates a point of attachment to the adjacent oxygen or sulfur.



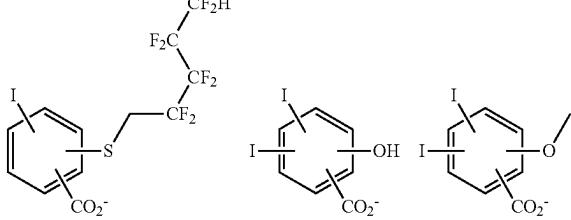
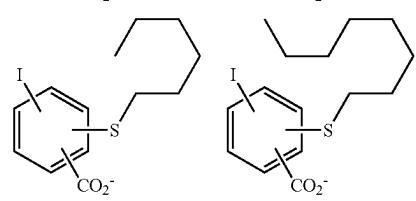
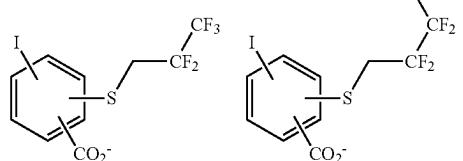
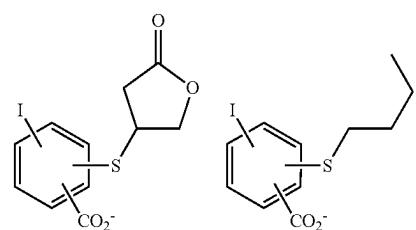
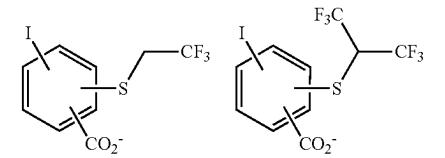
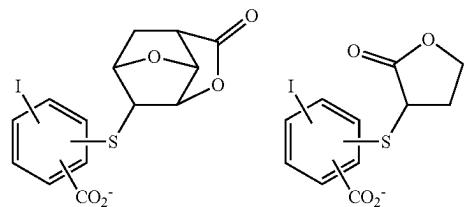
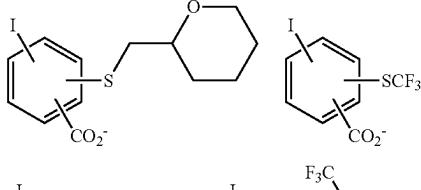
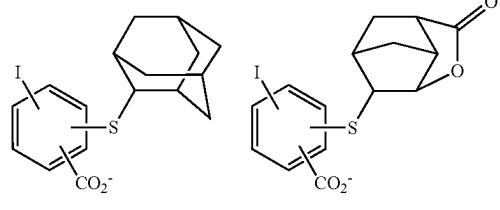
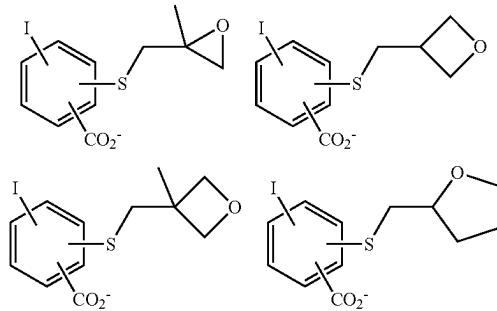
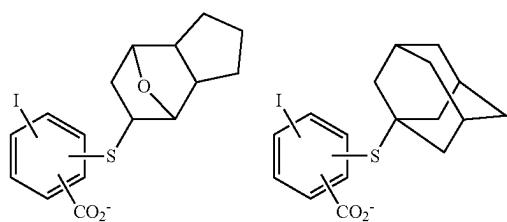
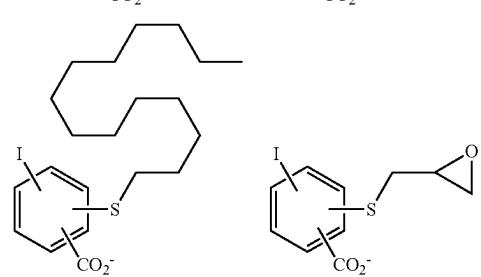
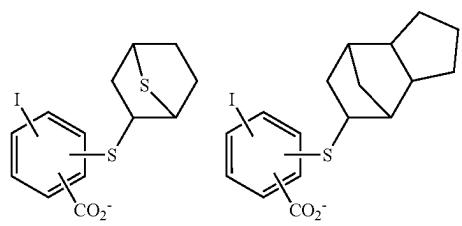
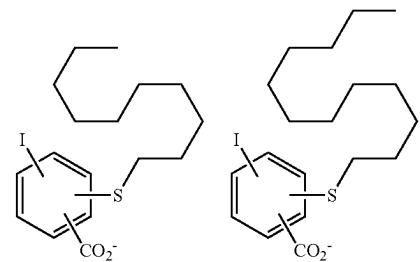




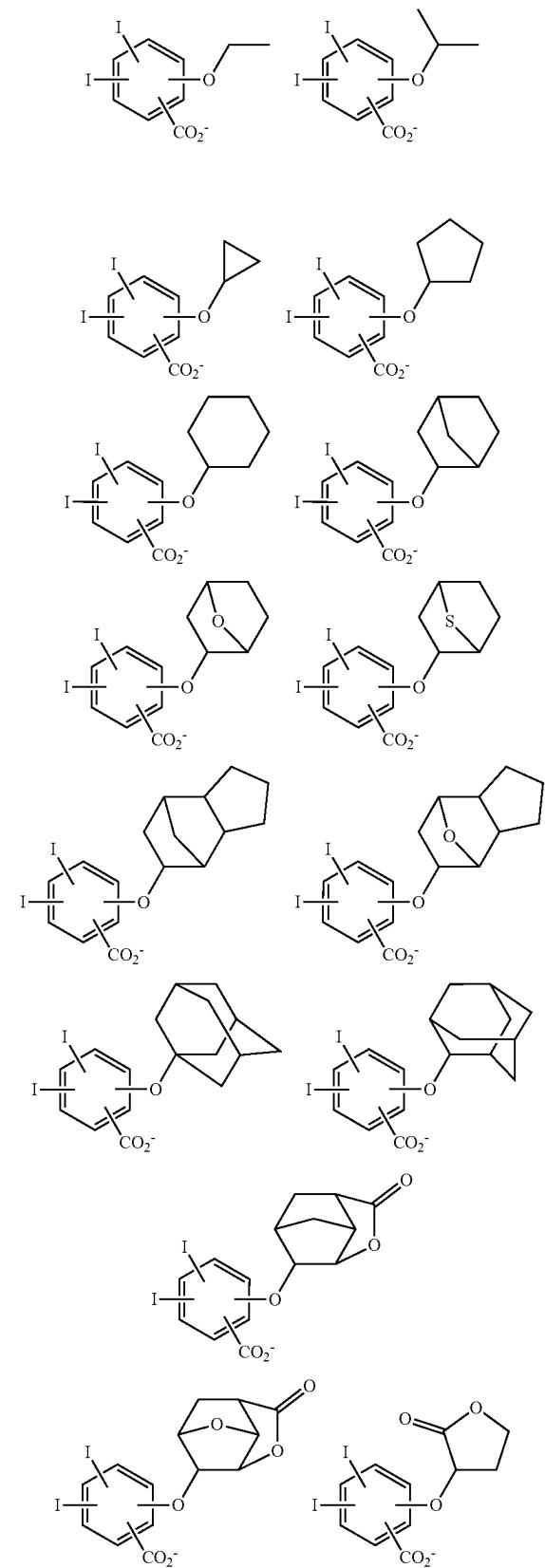
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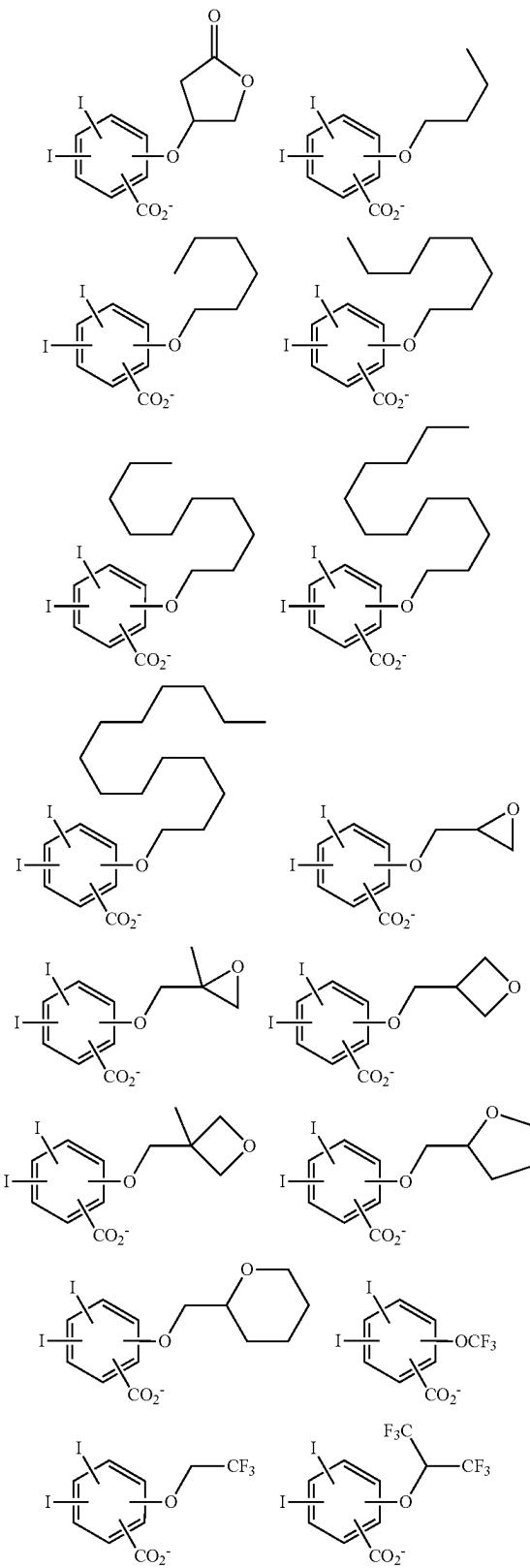
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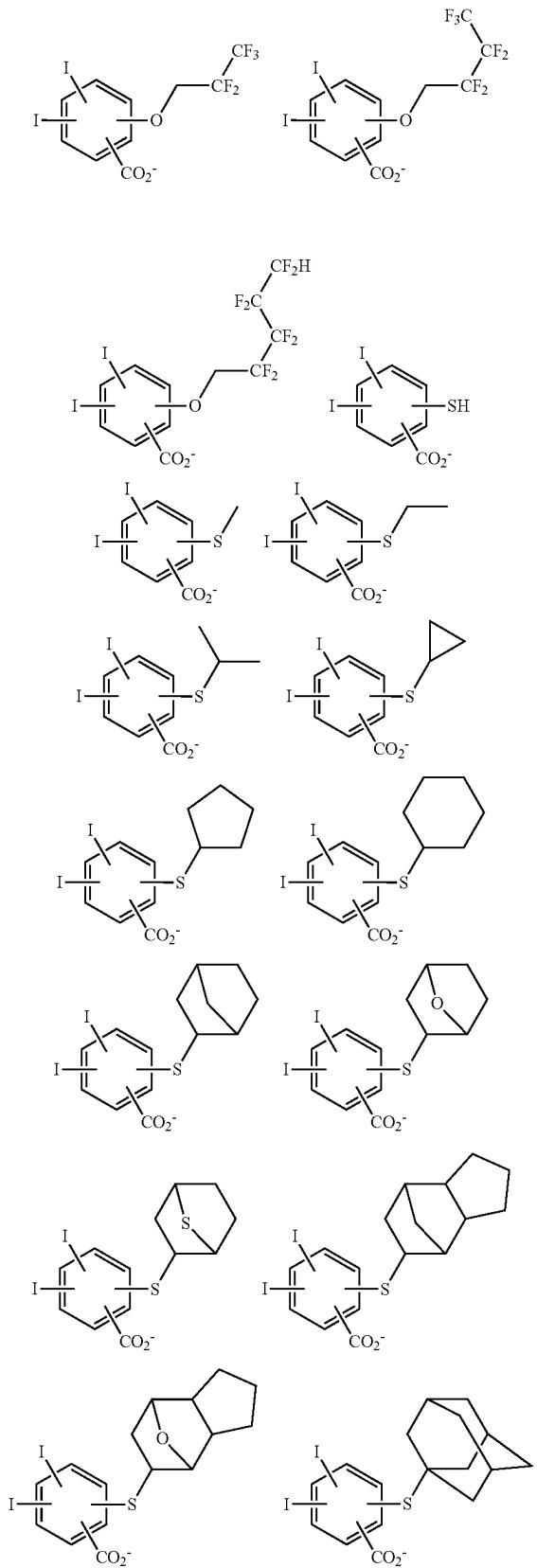
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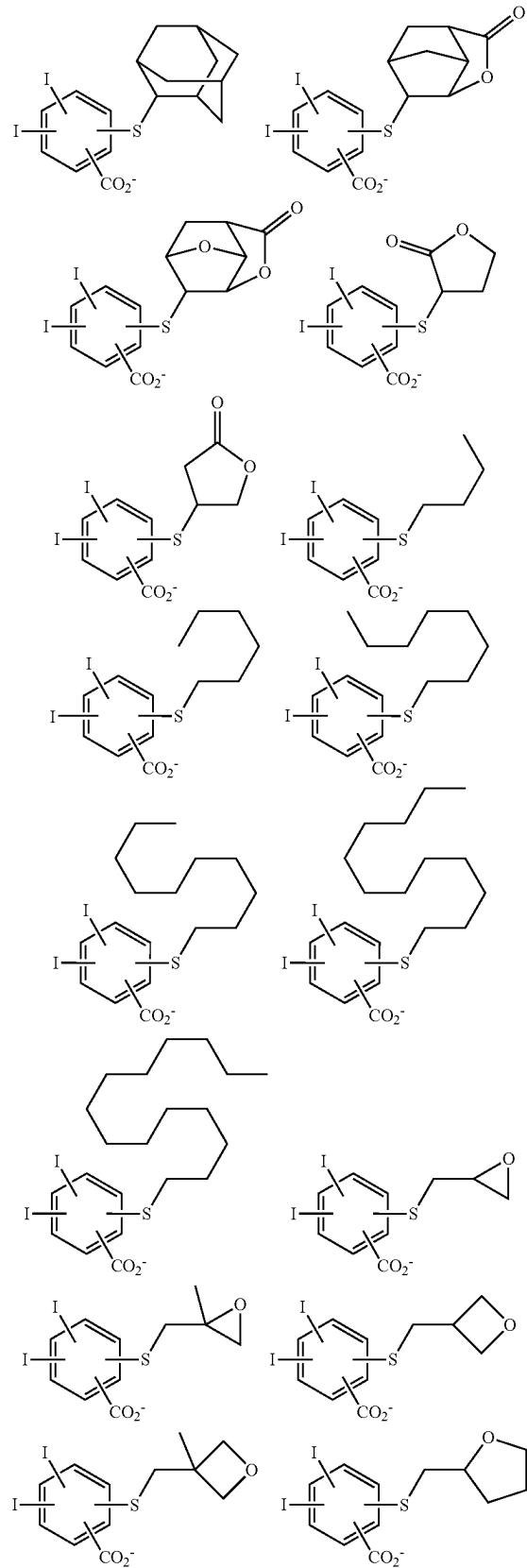
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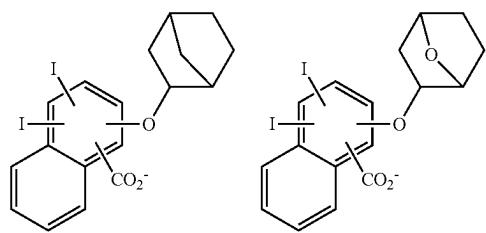
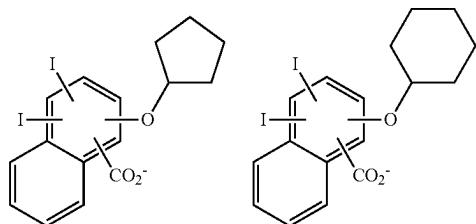
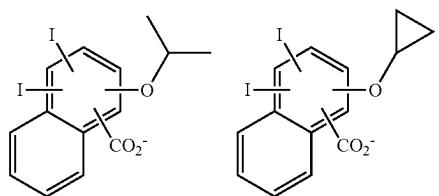
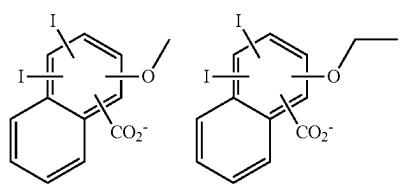
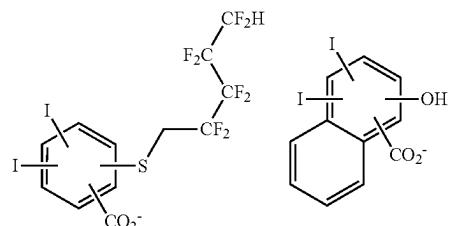
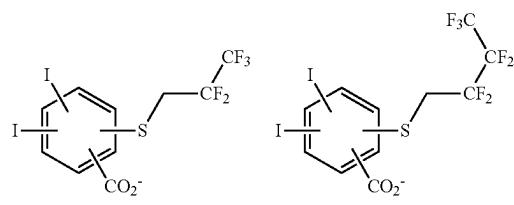
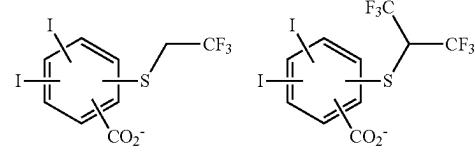
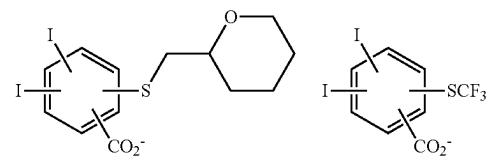
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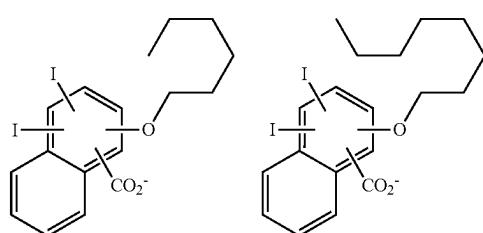
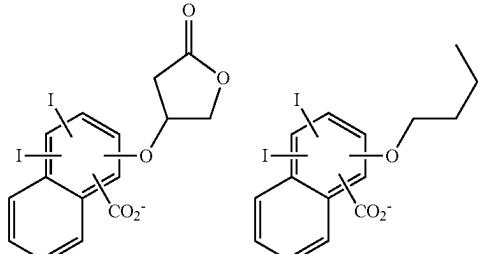
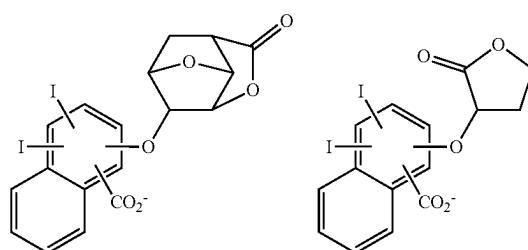
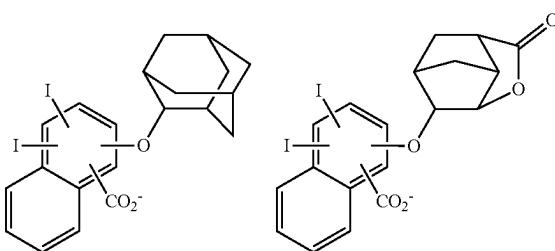
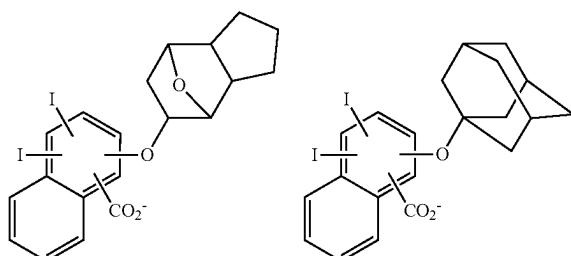
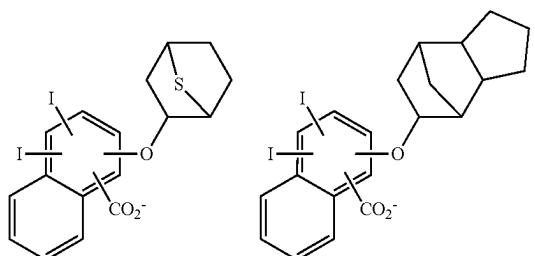
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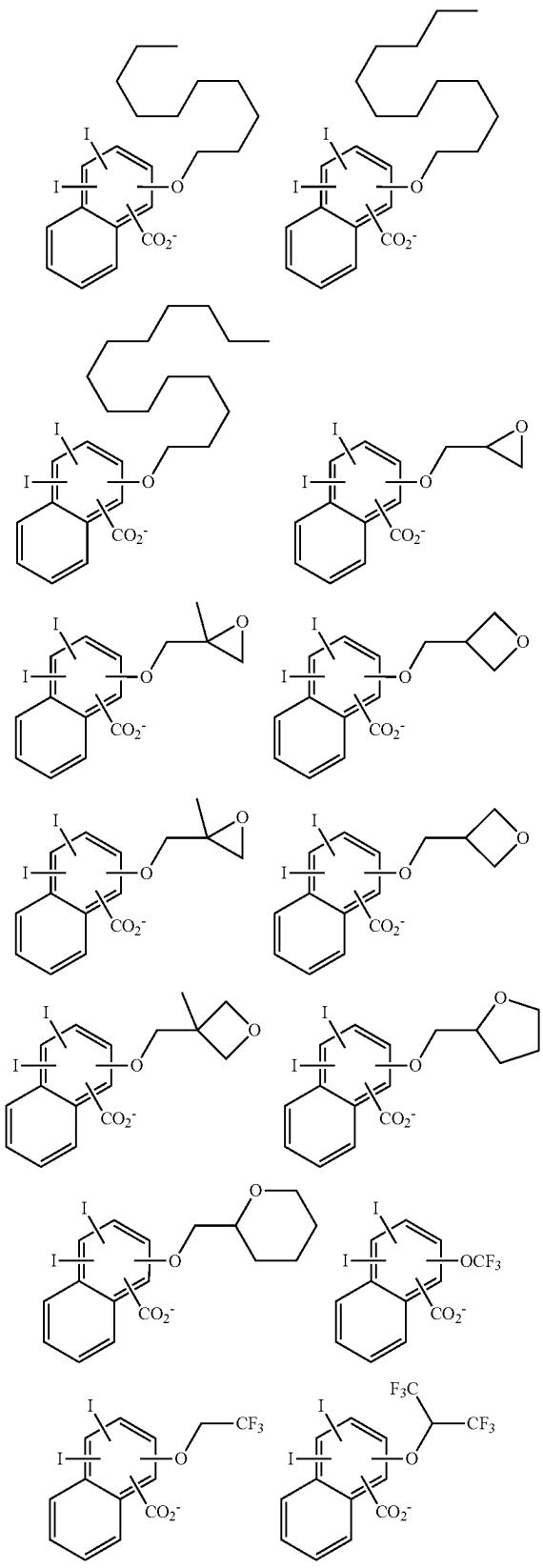
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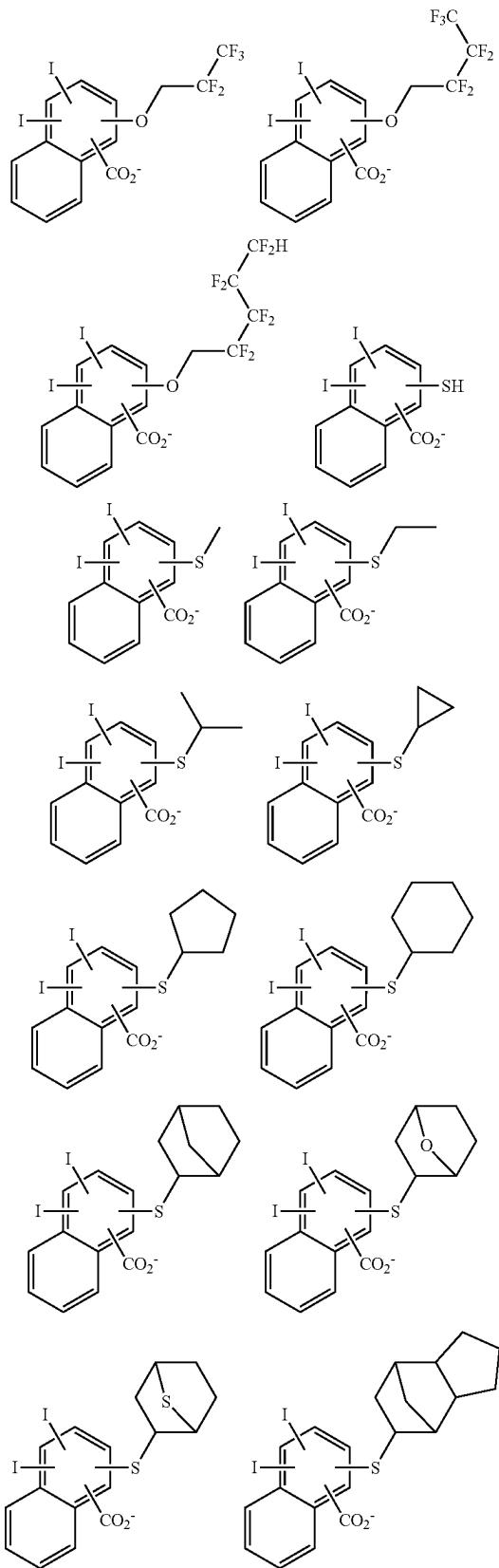
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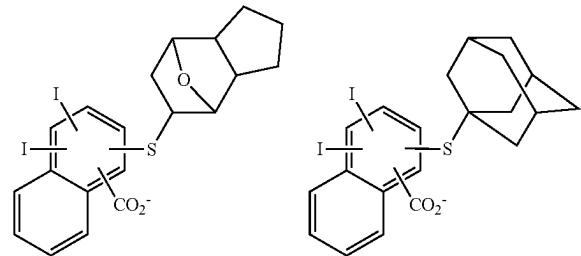
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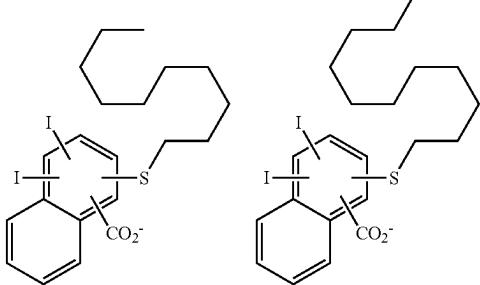
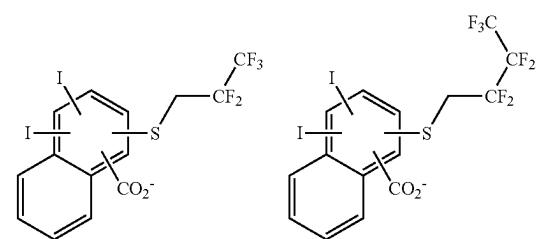
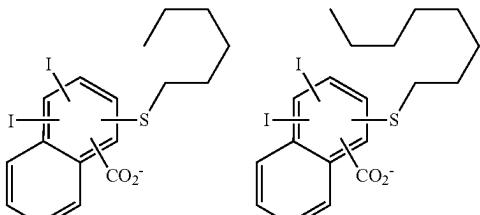
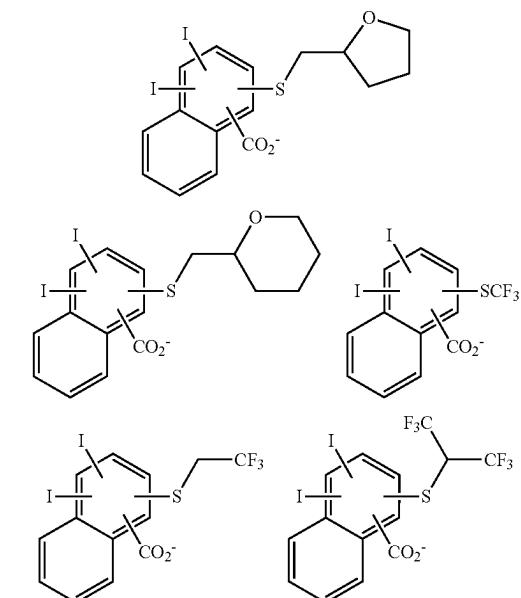
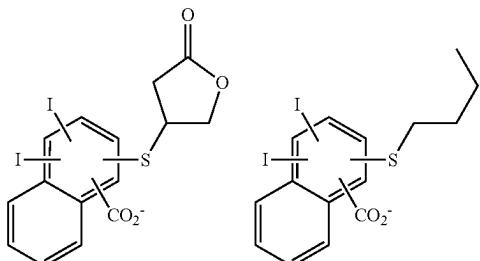
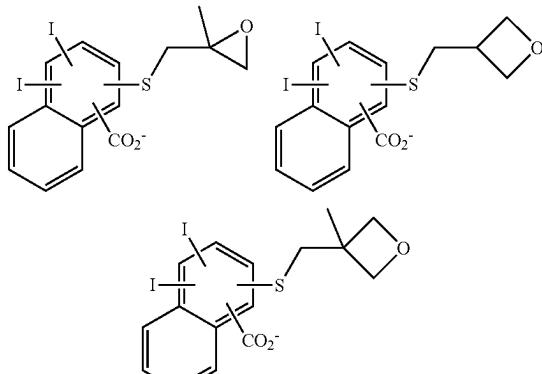
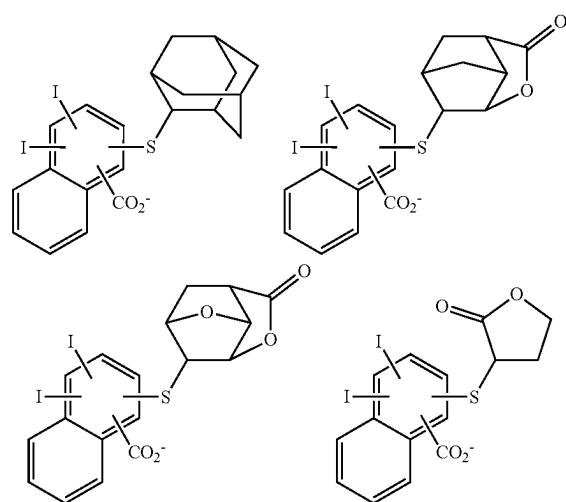
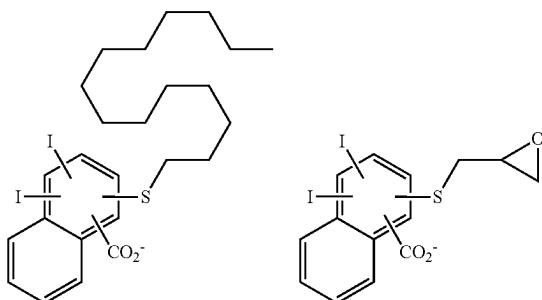
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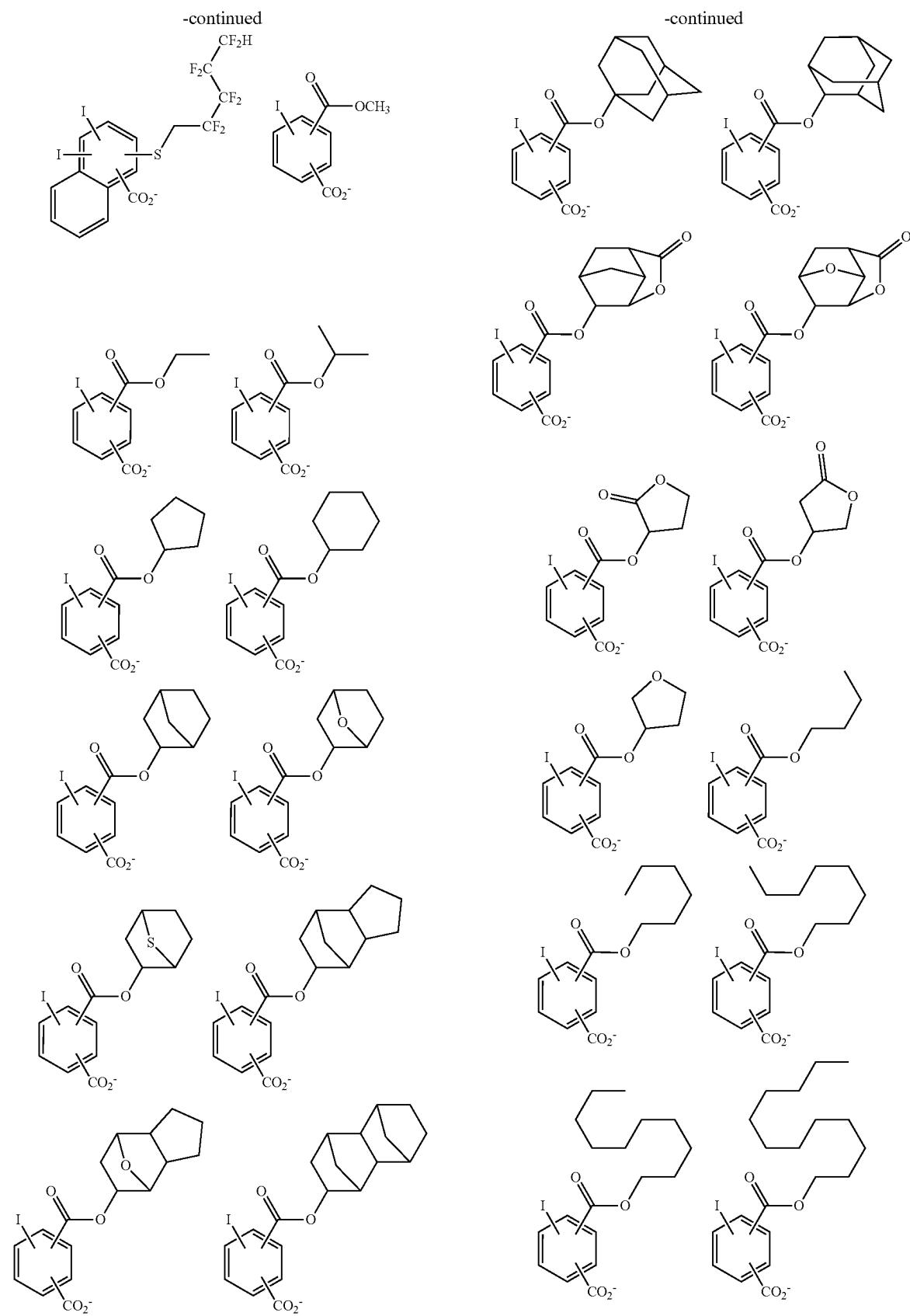


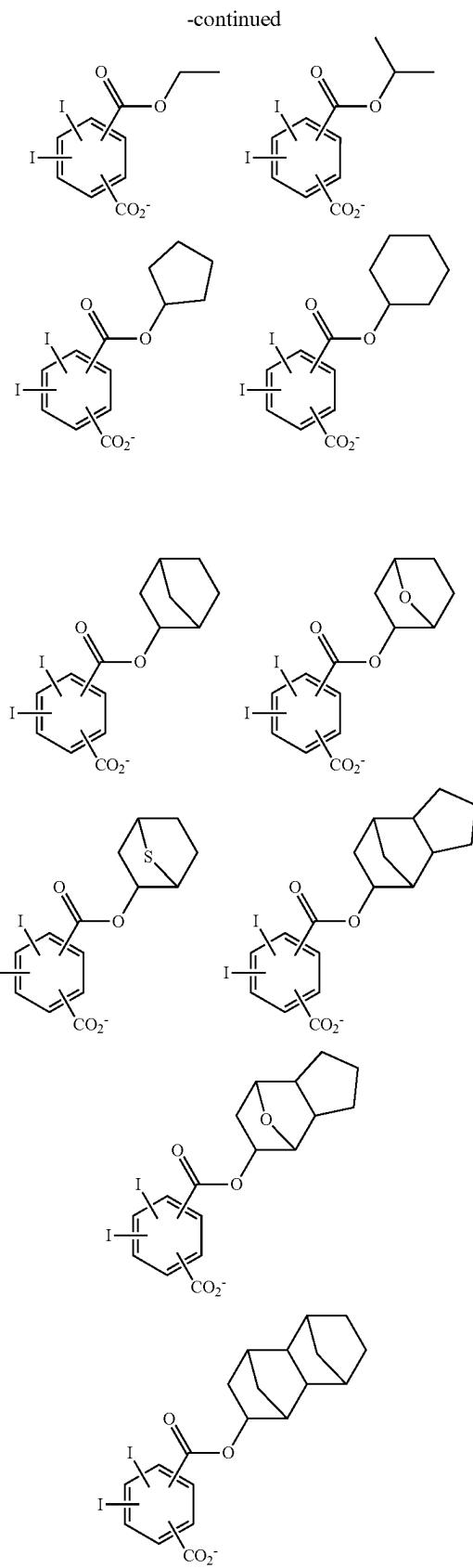
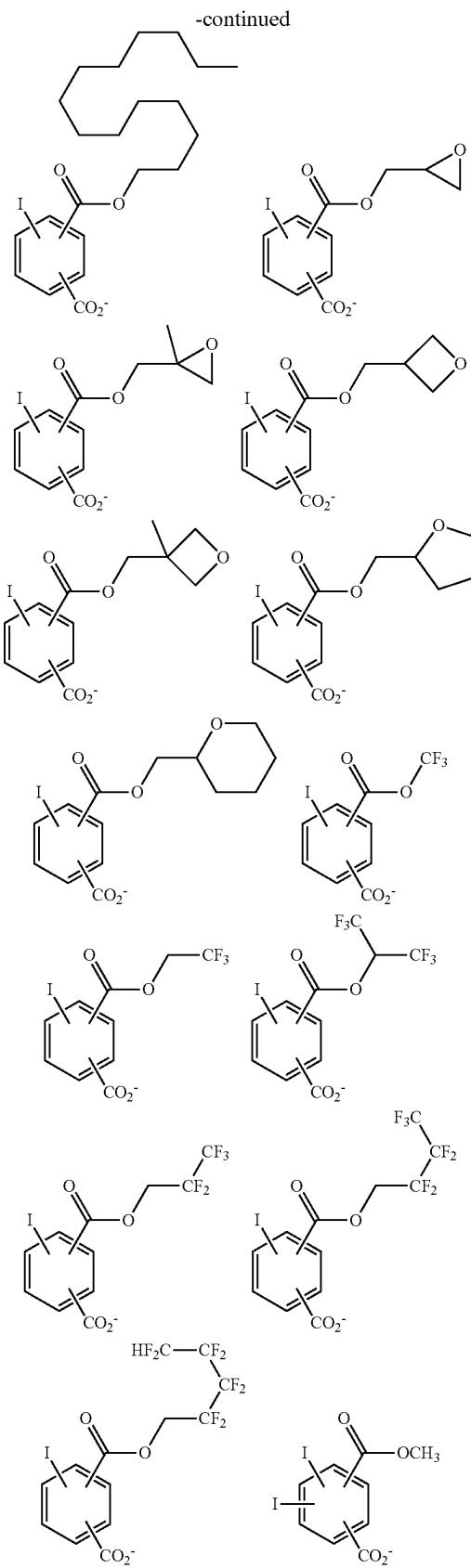
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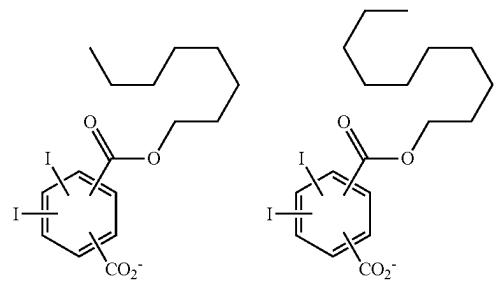
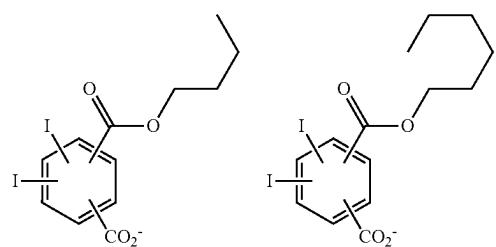
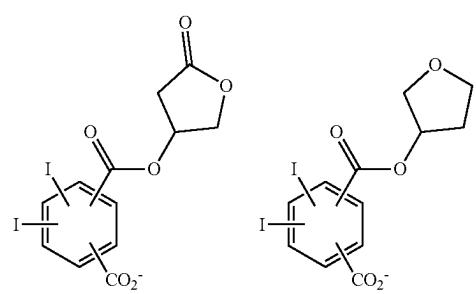
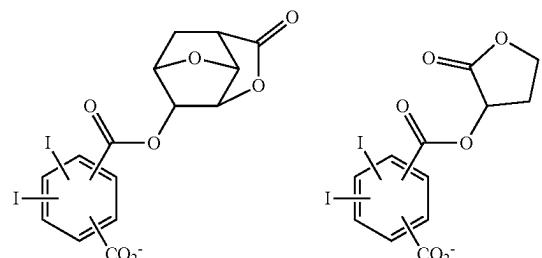
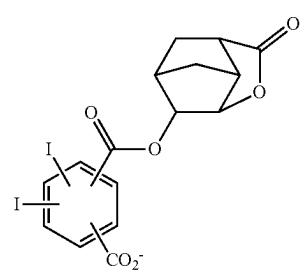
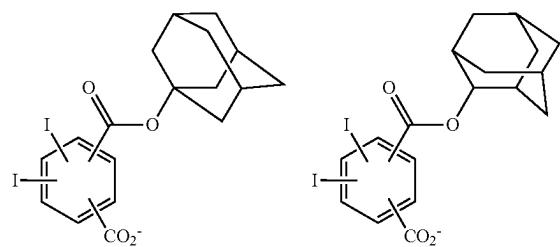
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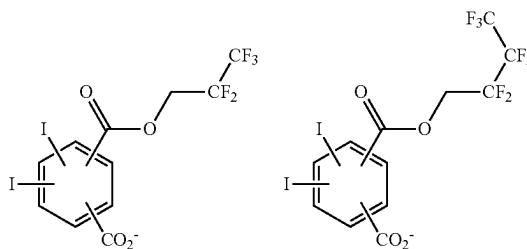
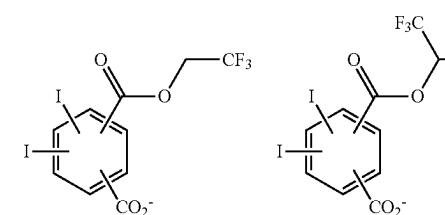
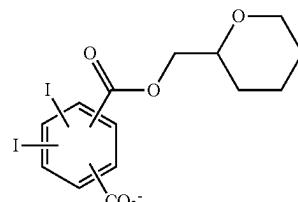
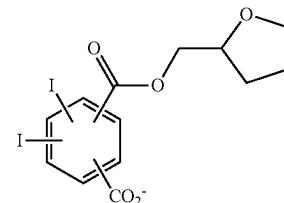
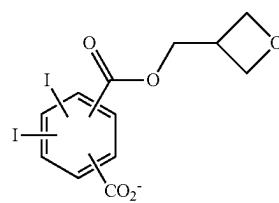
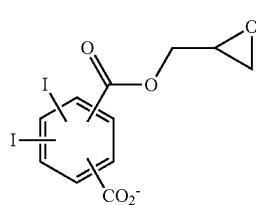
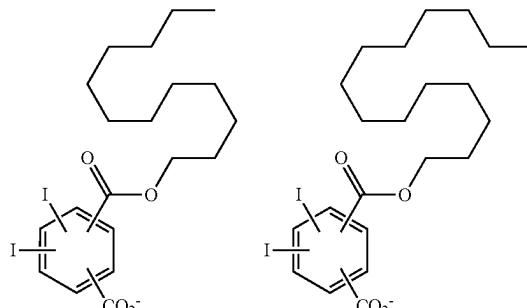


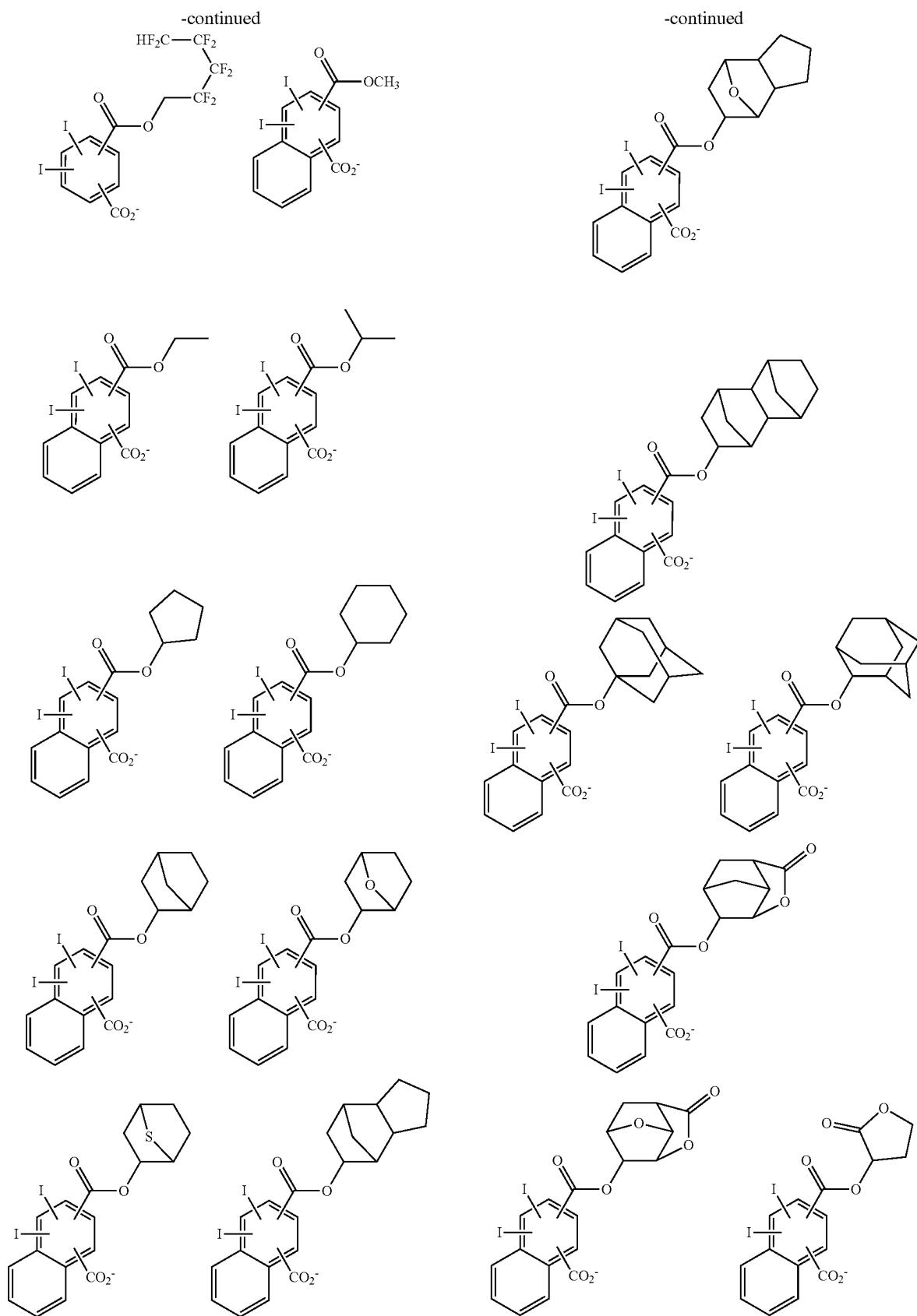


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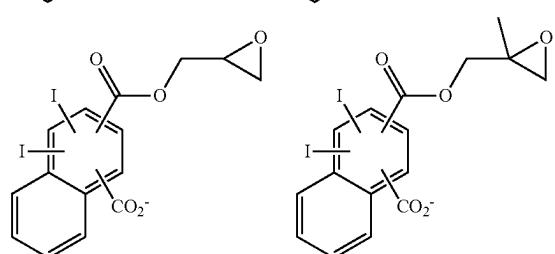
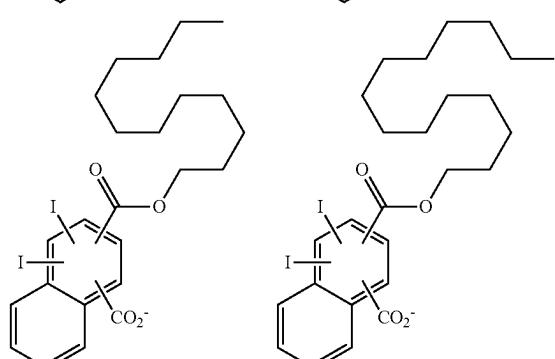
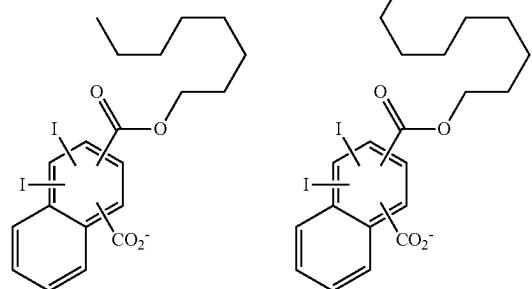
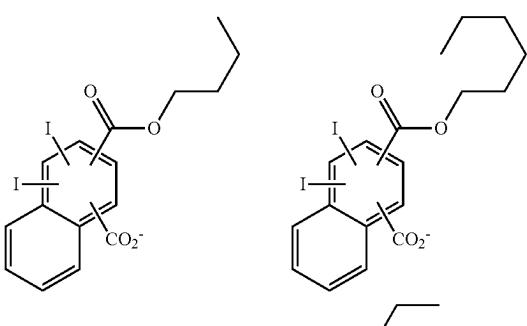
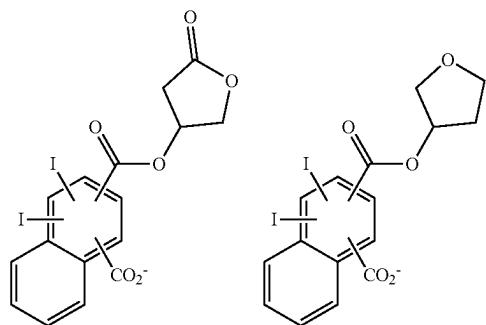


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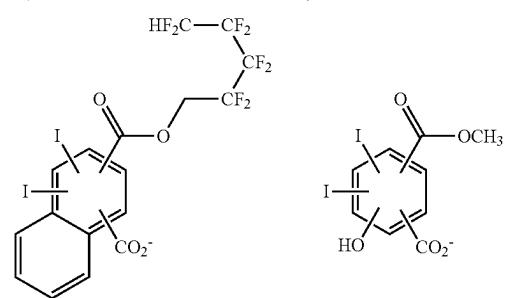
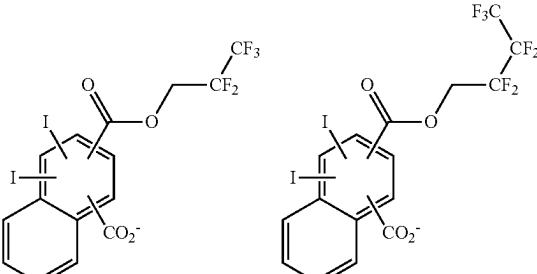
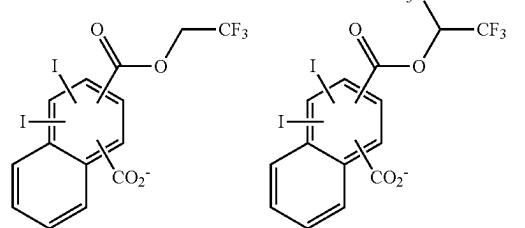
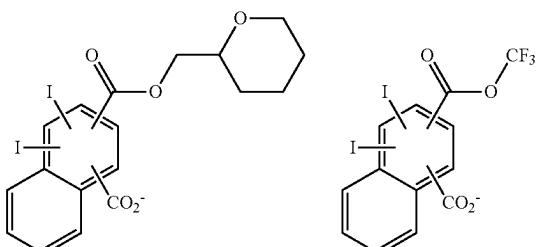
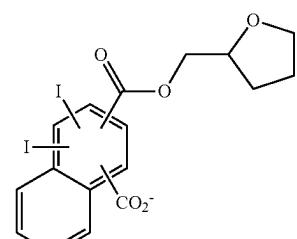
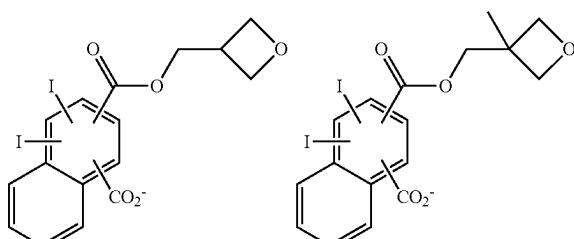




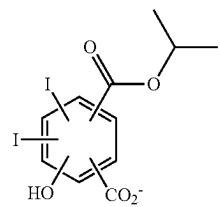
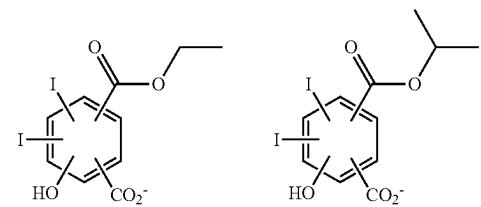
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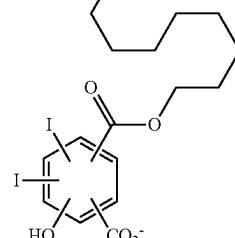
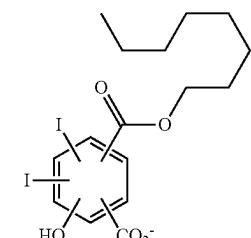
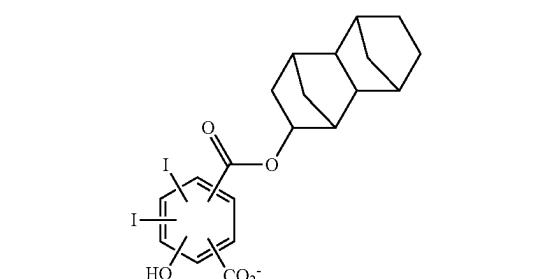
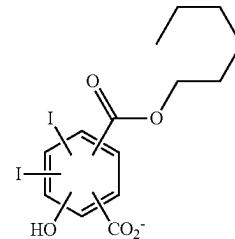
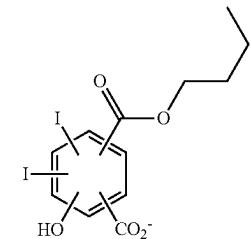
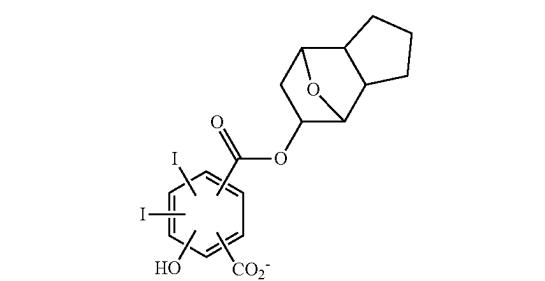
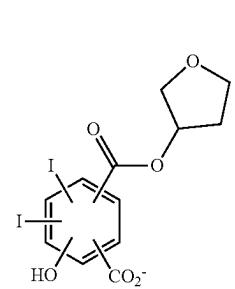
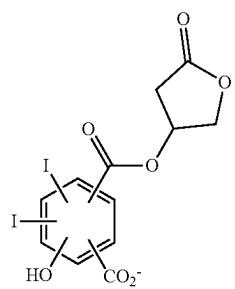
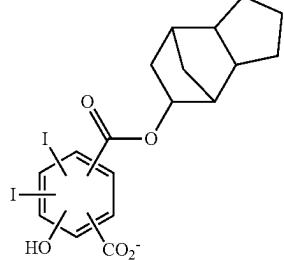
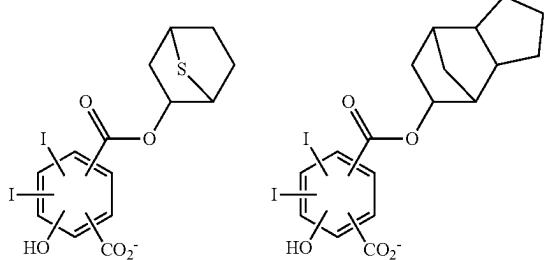
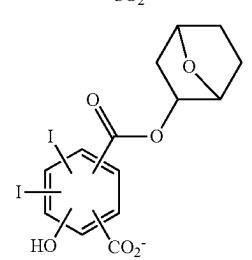
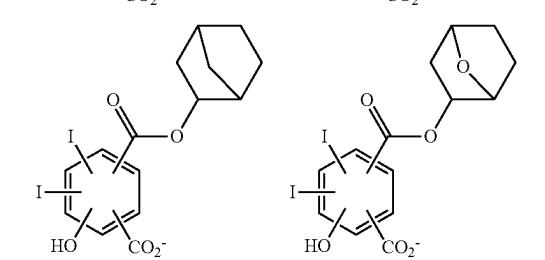
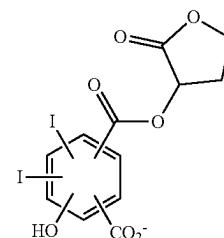
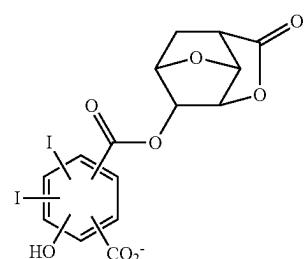
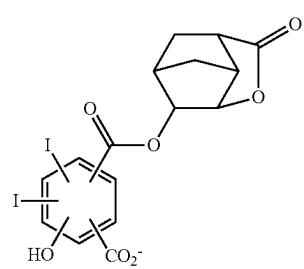
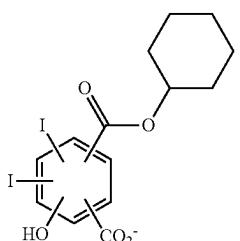
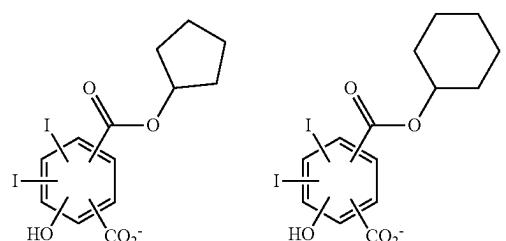
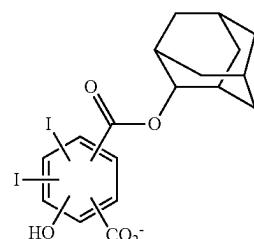
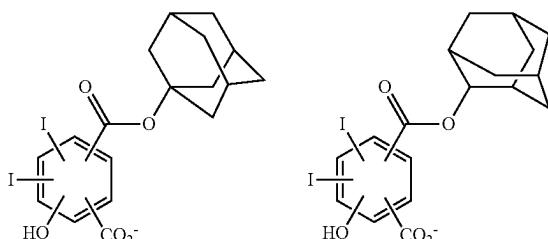
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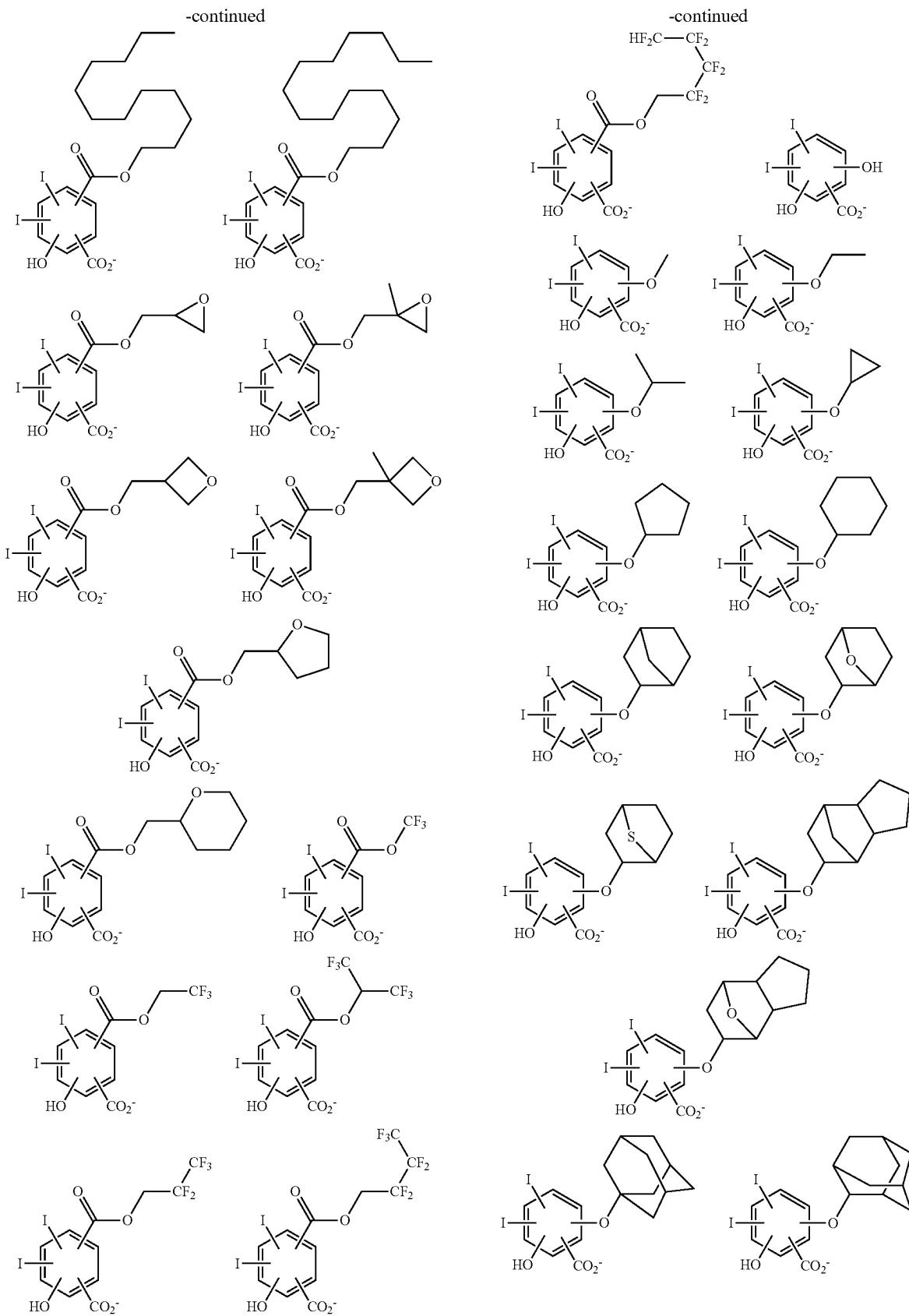


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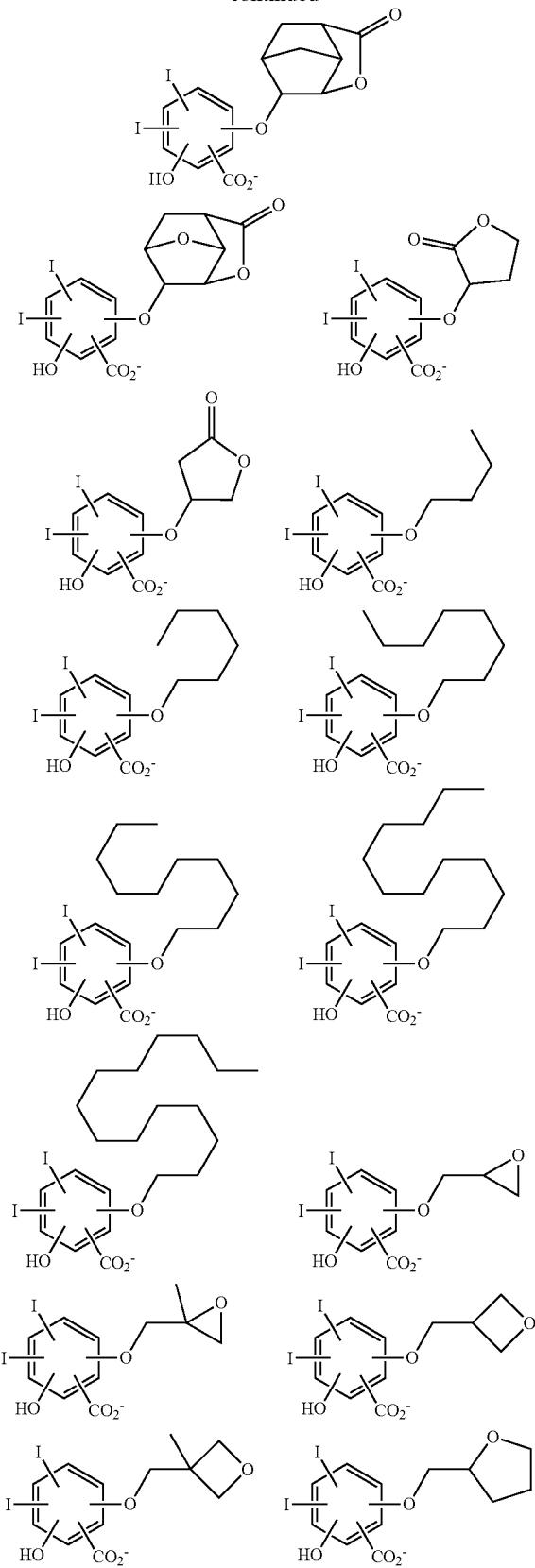


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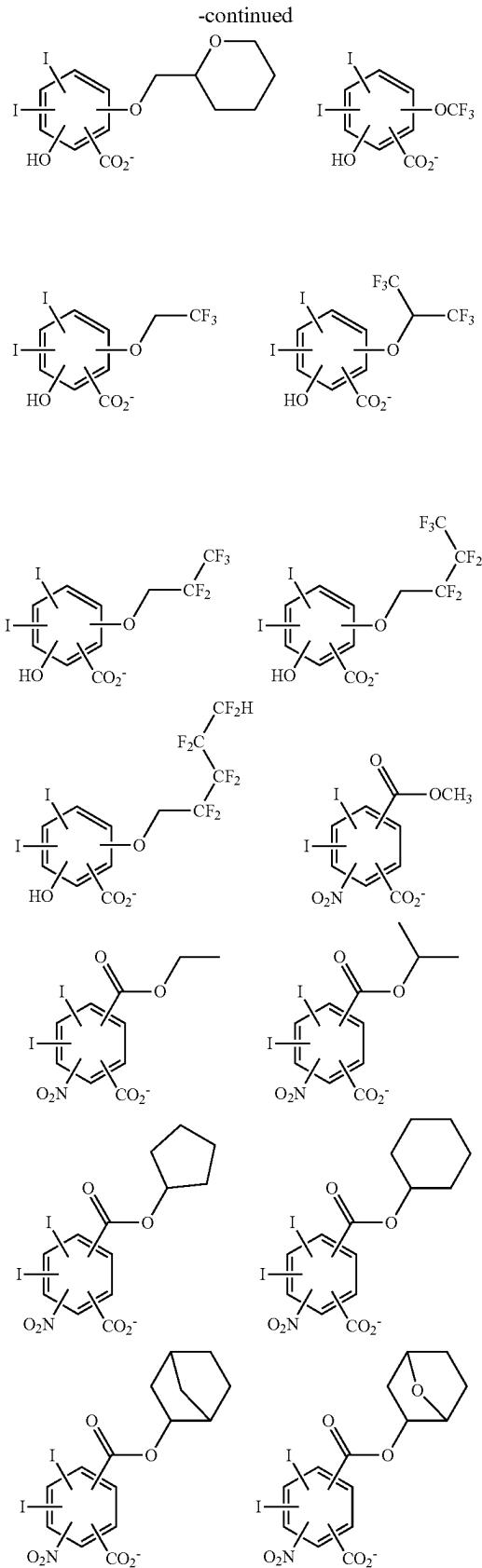




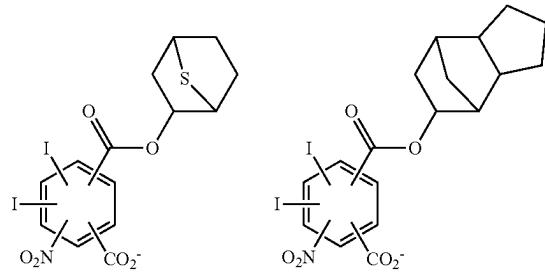
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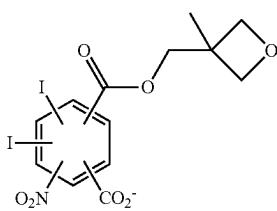
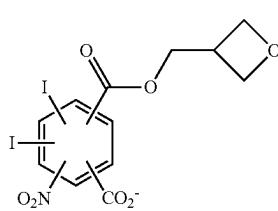
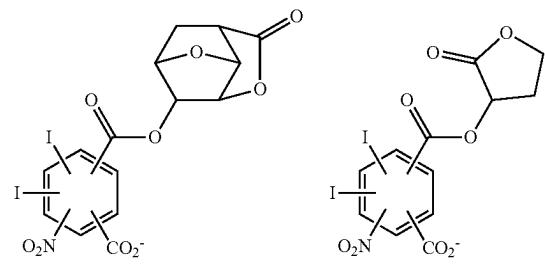
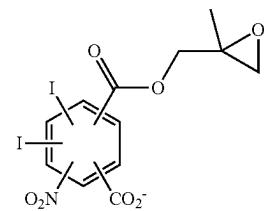
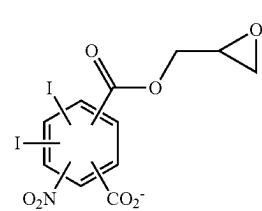
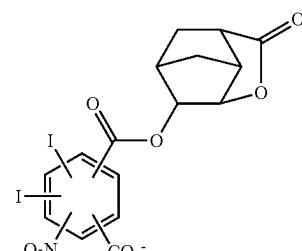
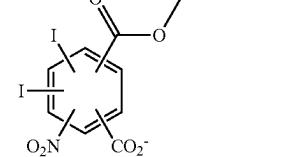
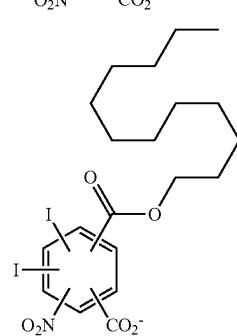
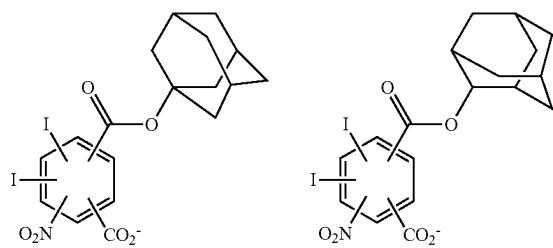
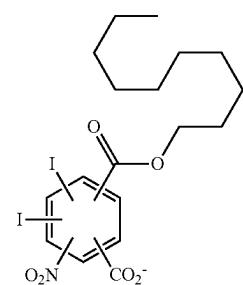
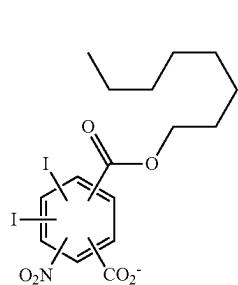
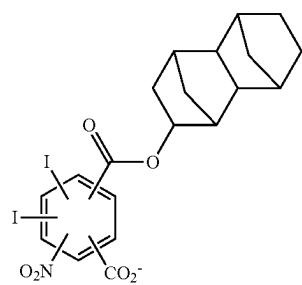
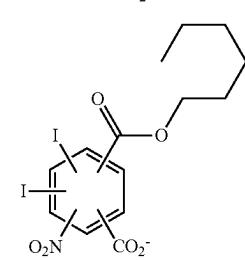
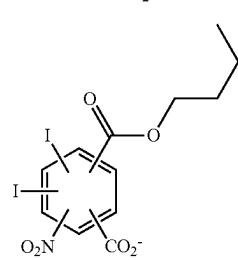
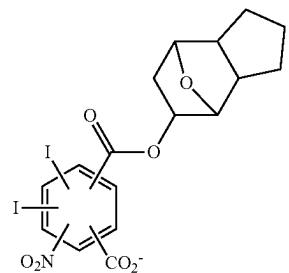
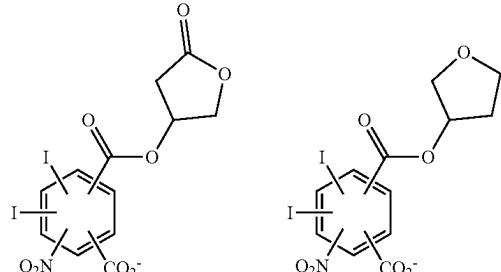
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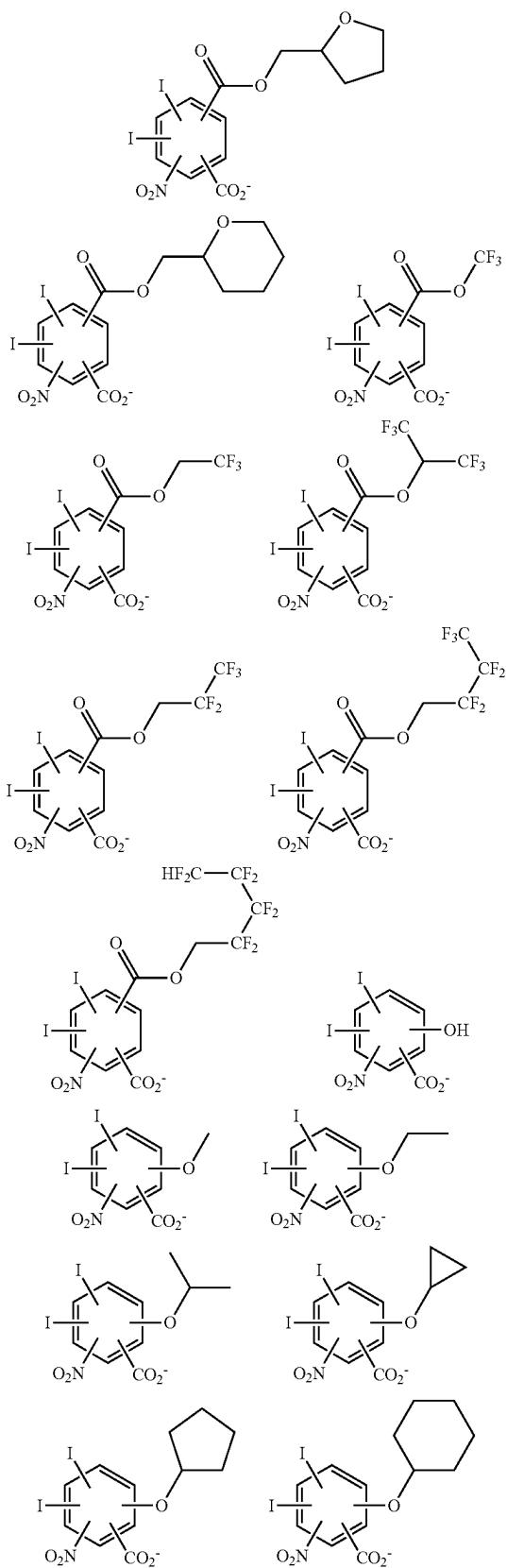
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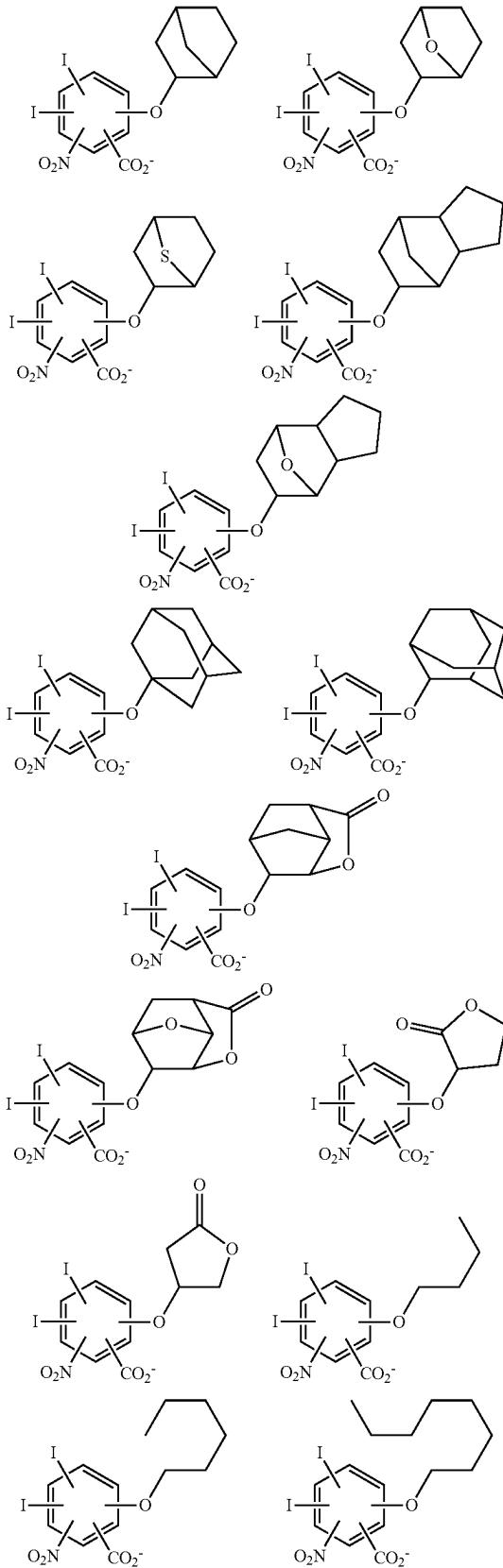
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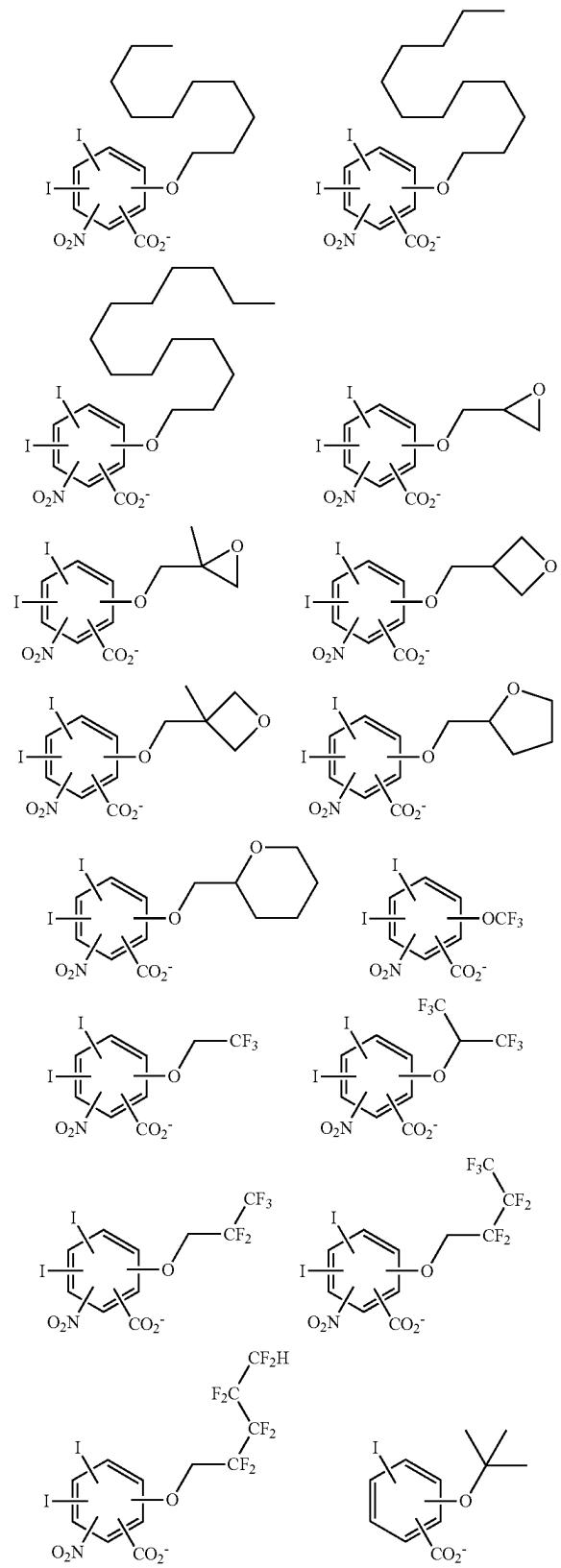
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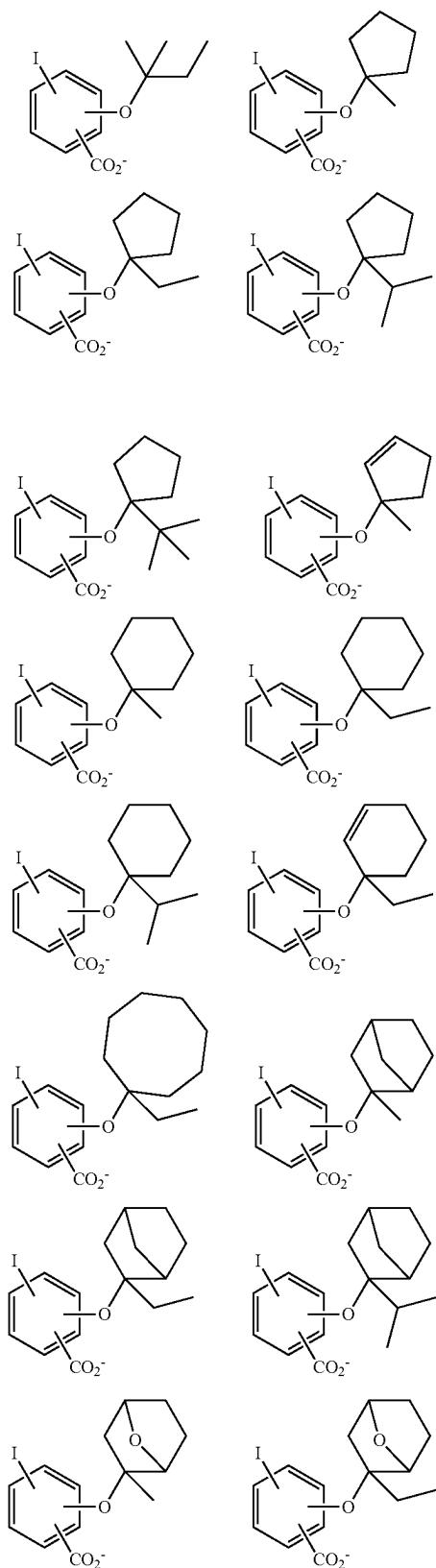
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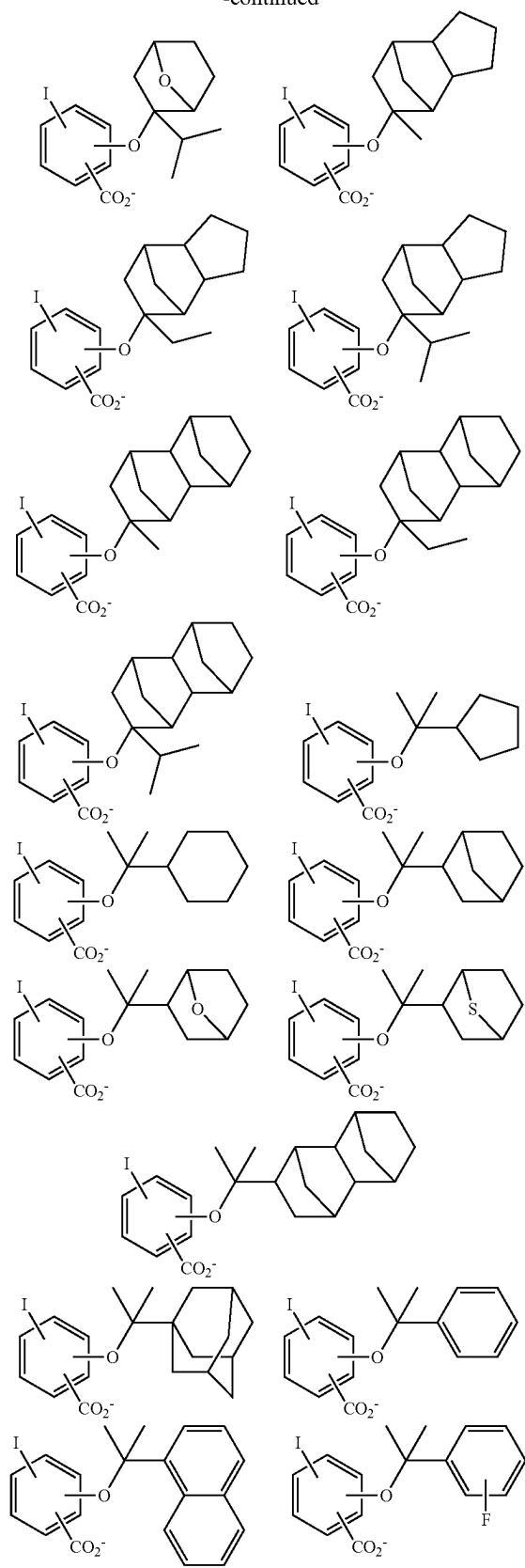
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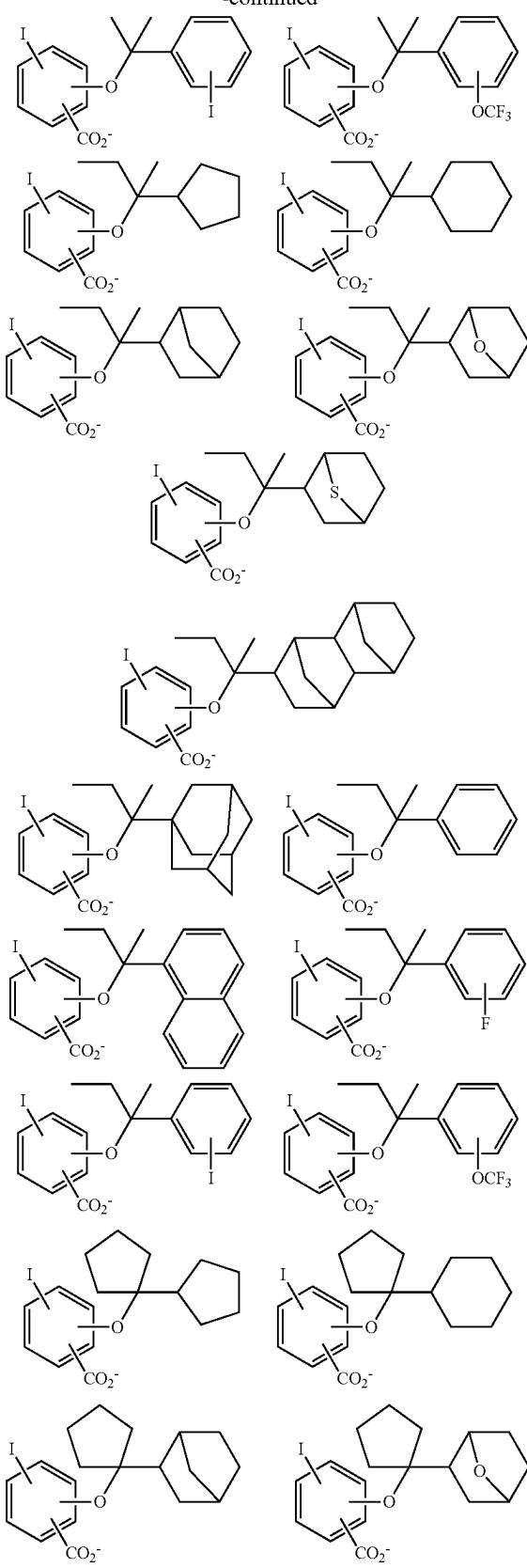
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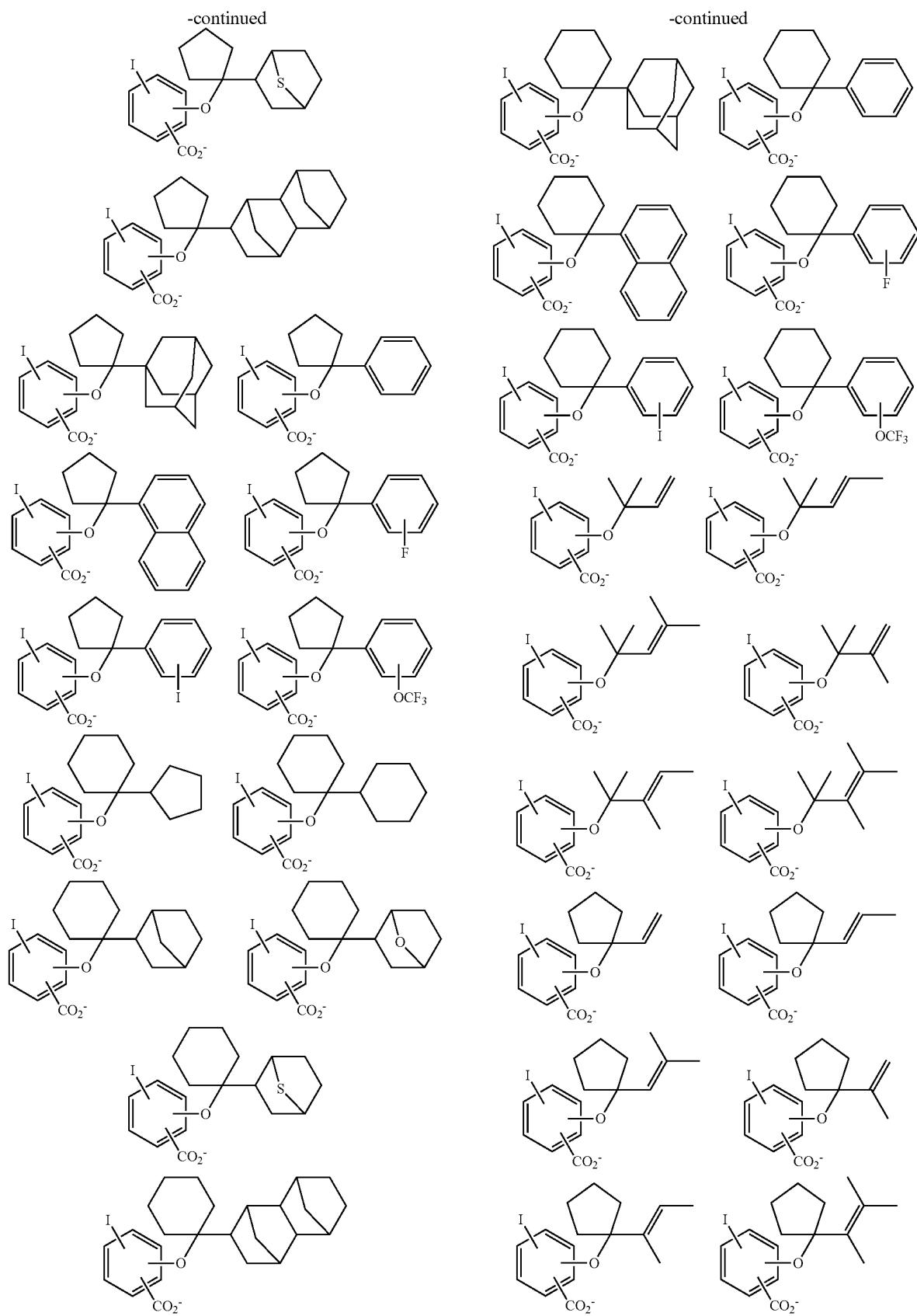


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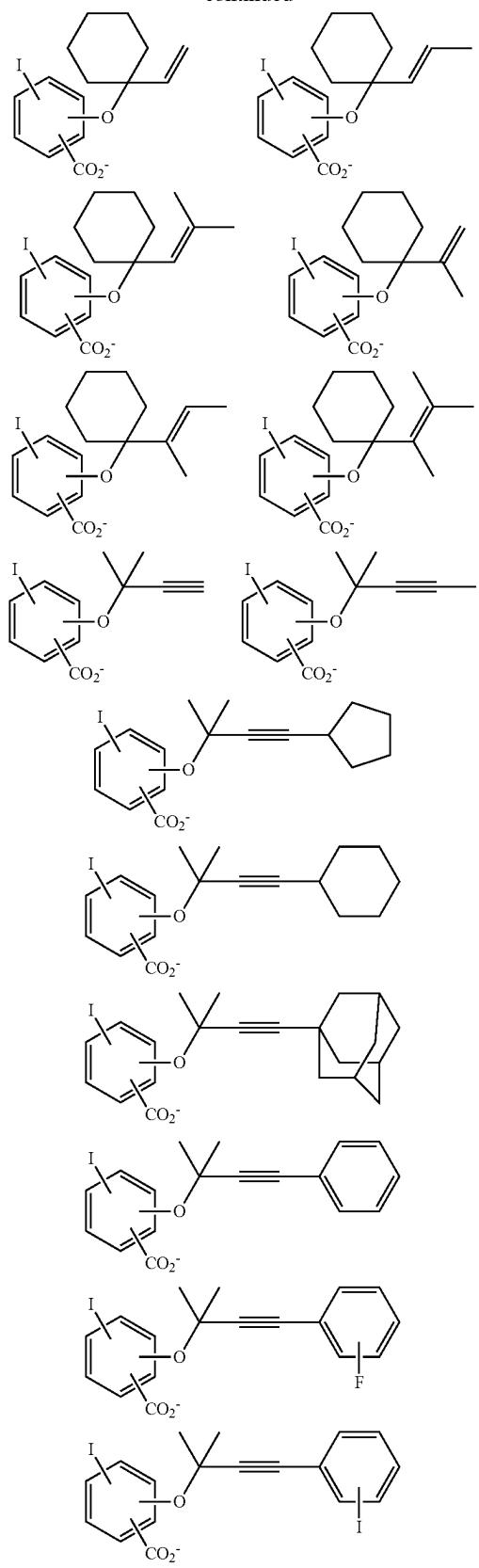


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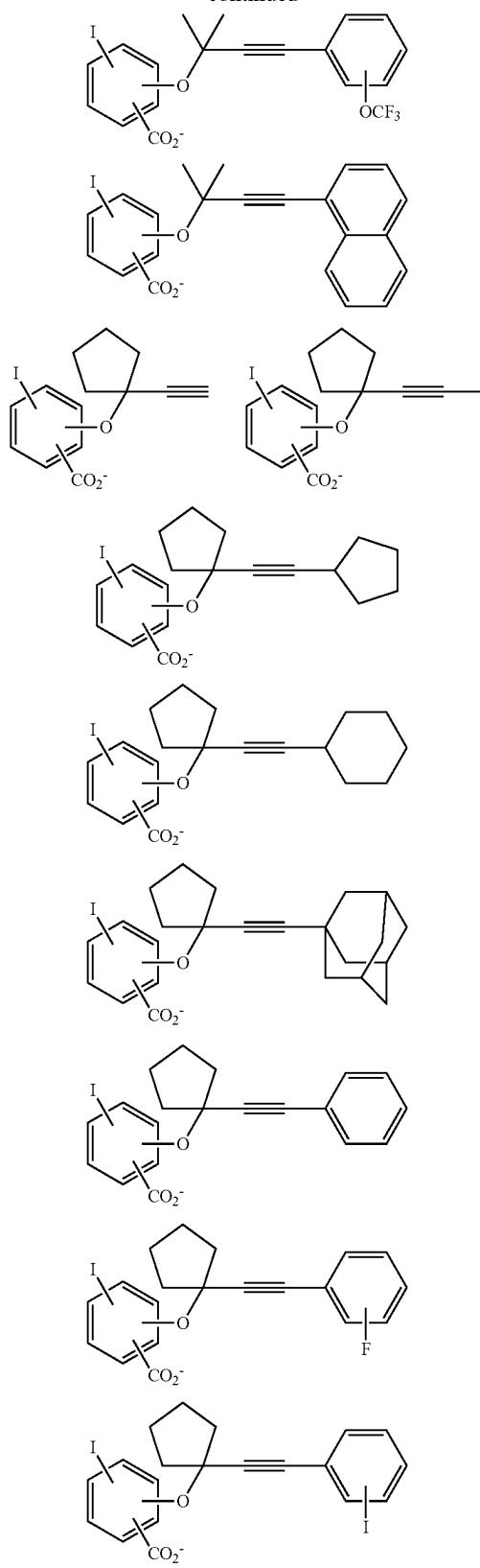


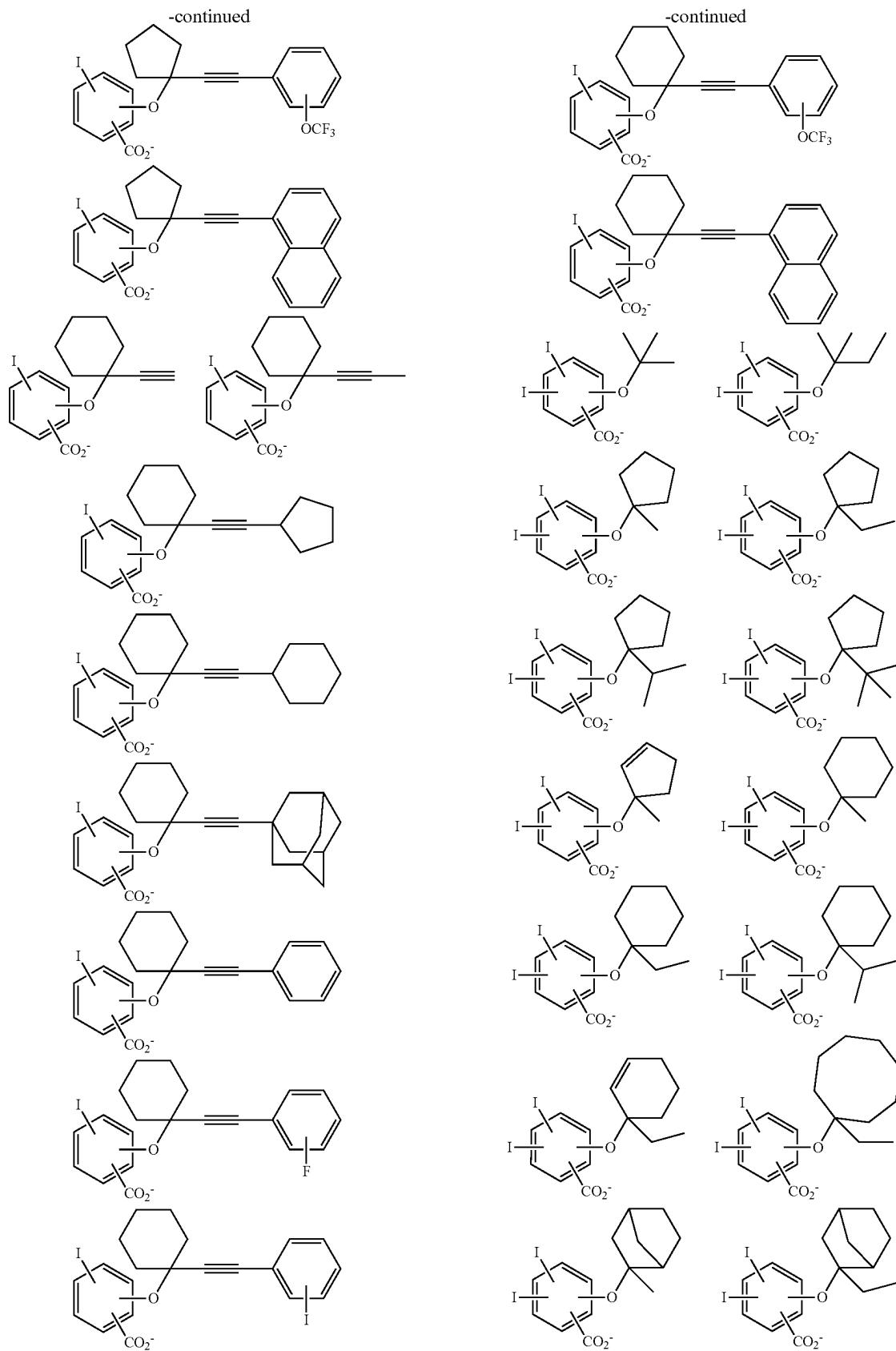


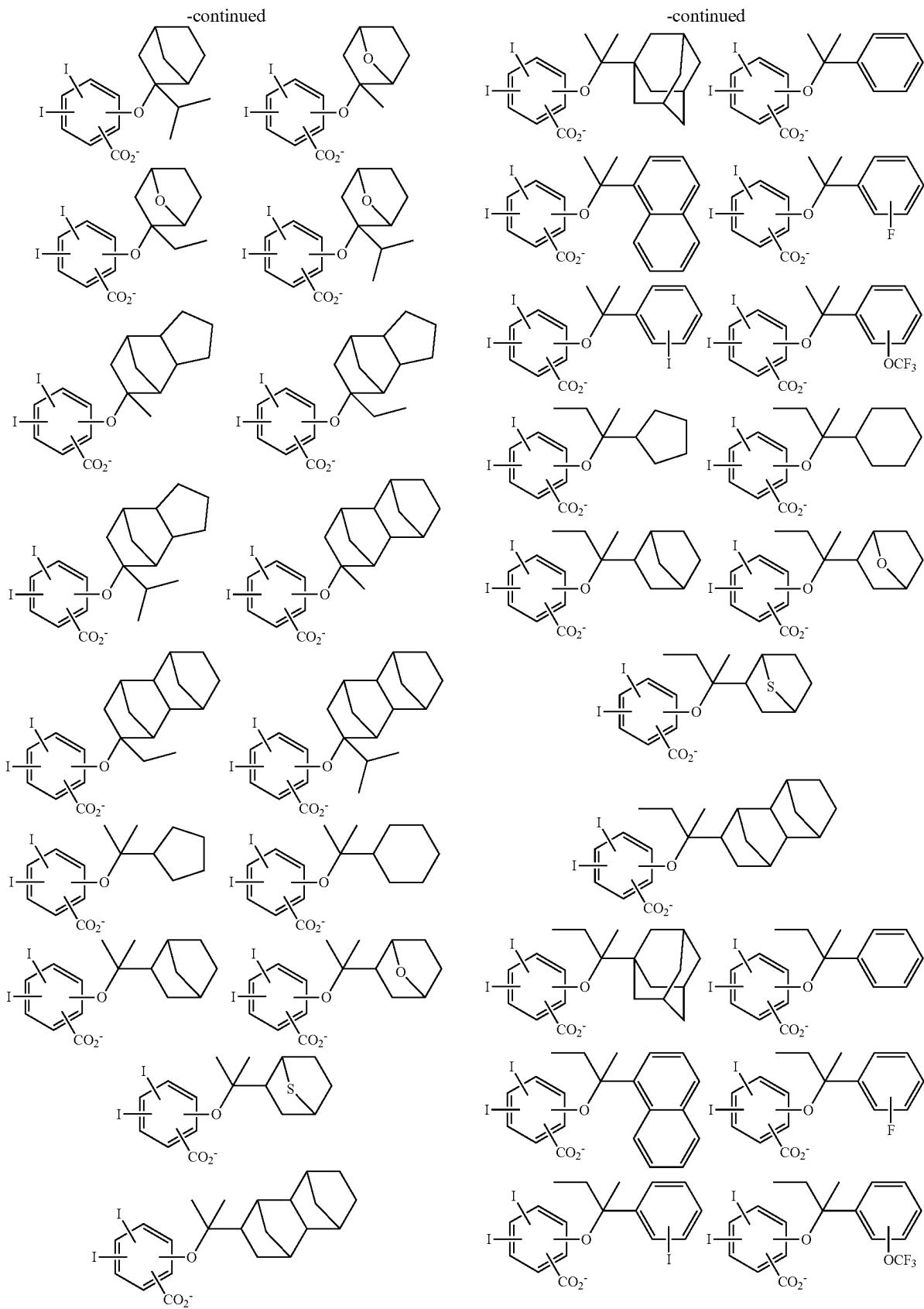
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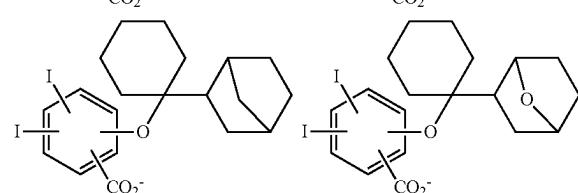
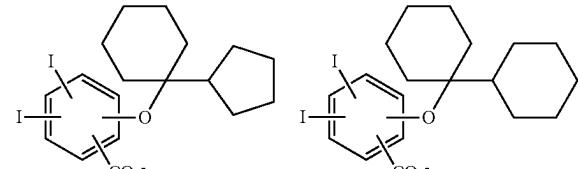
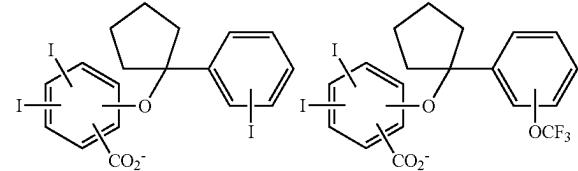
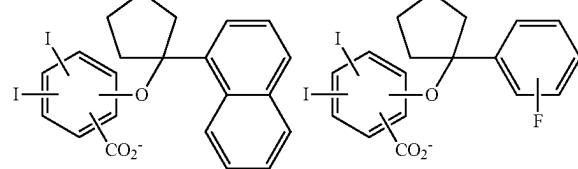
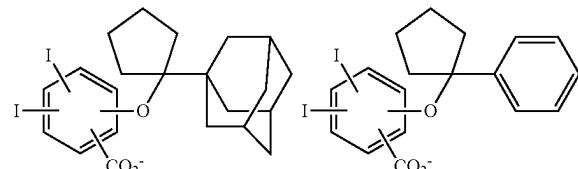
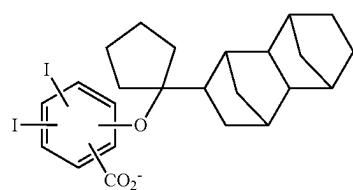
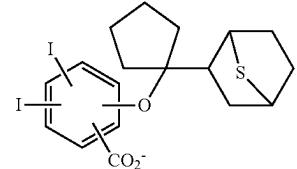
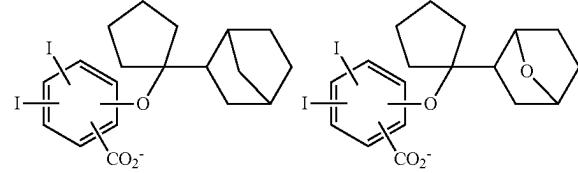
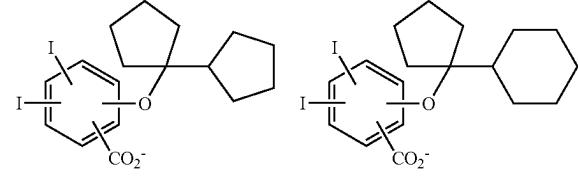
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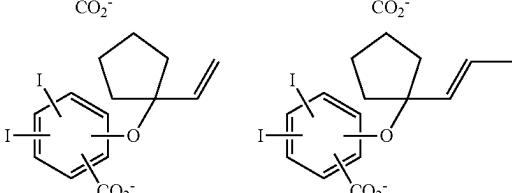
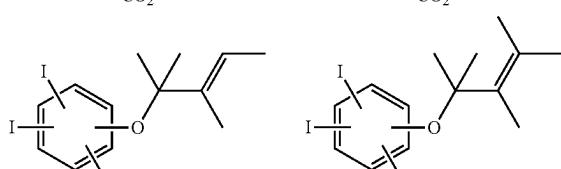
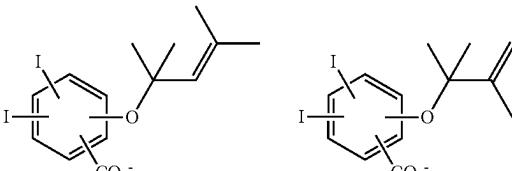
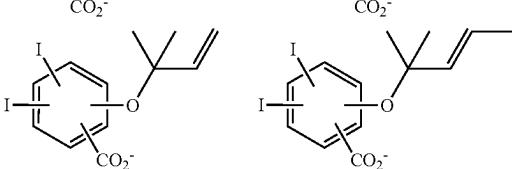
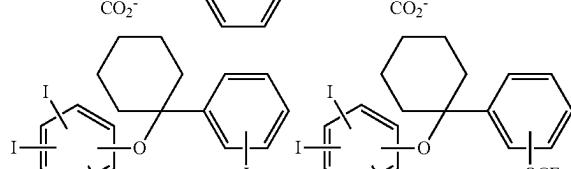
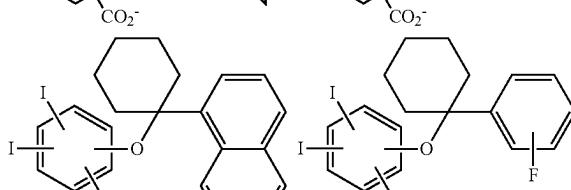
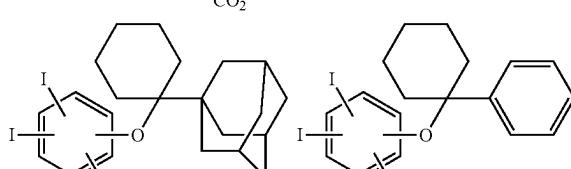
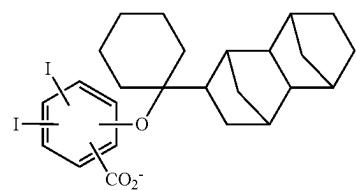
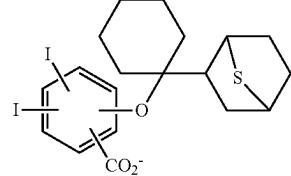




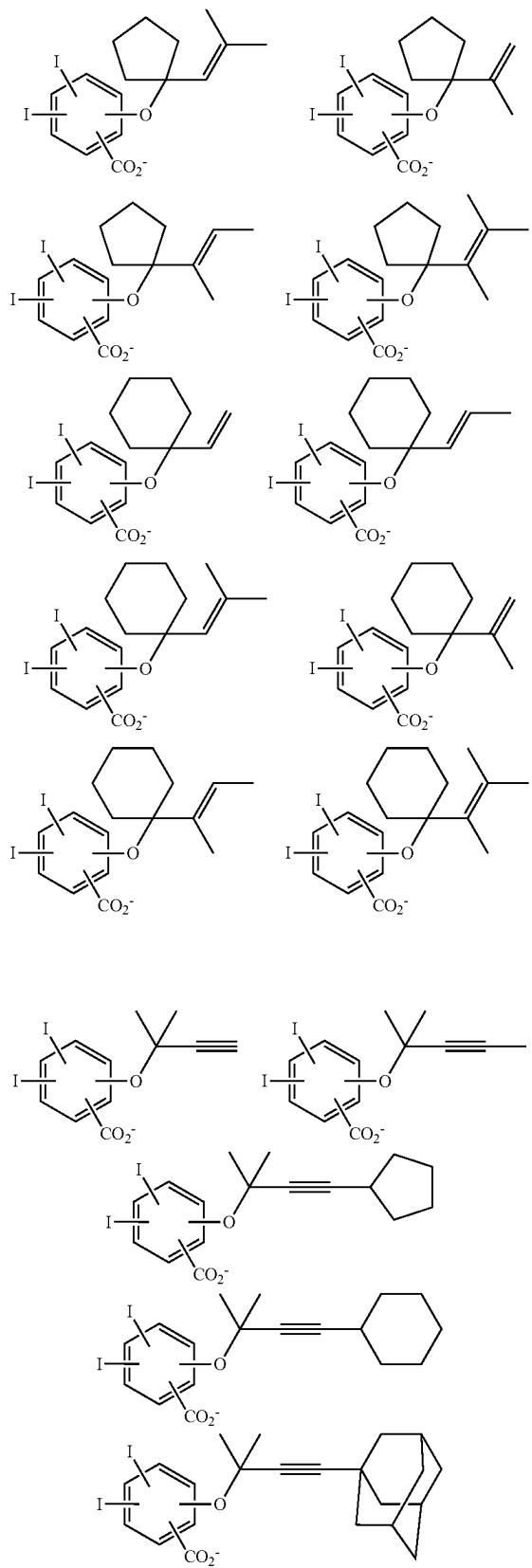
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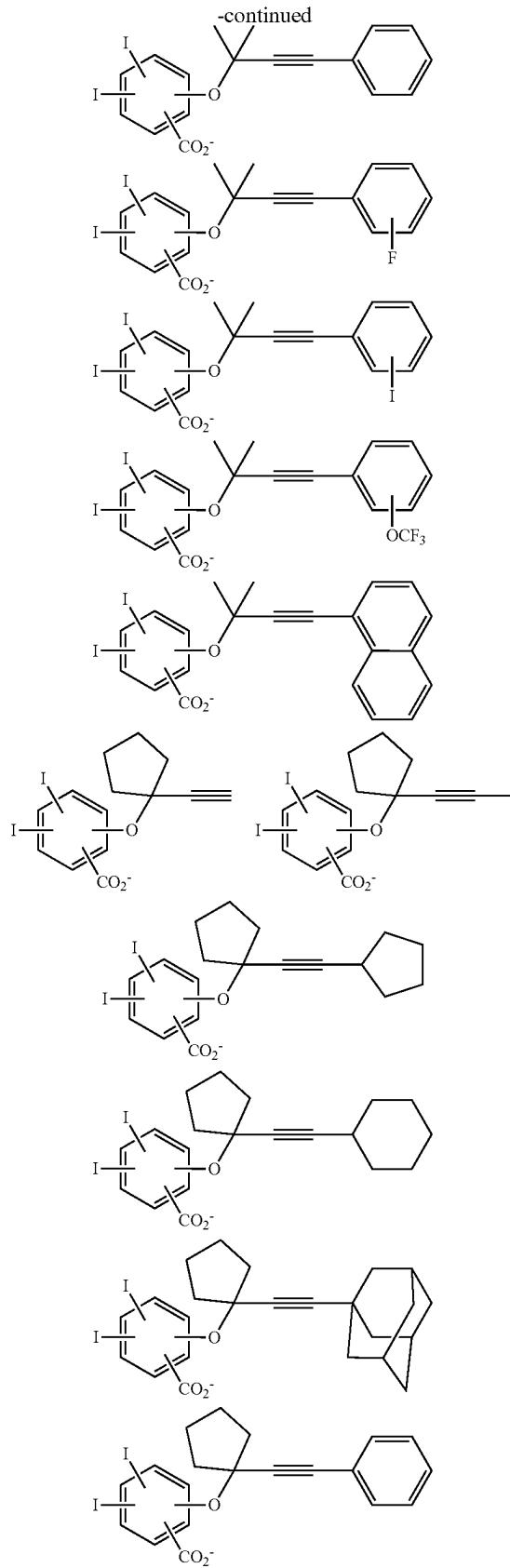
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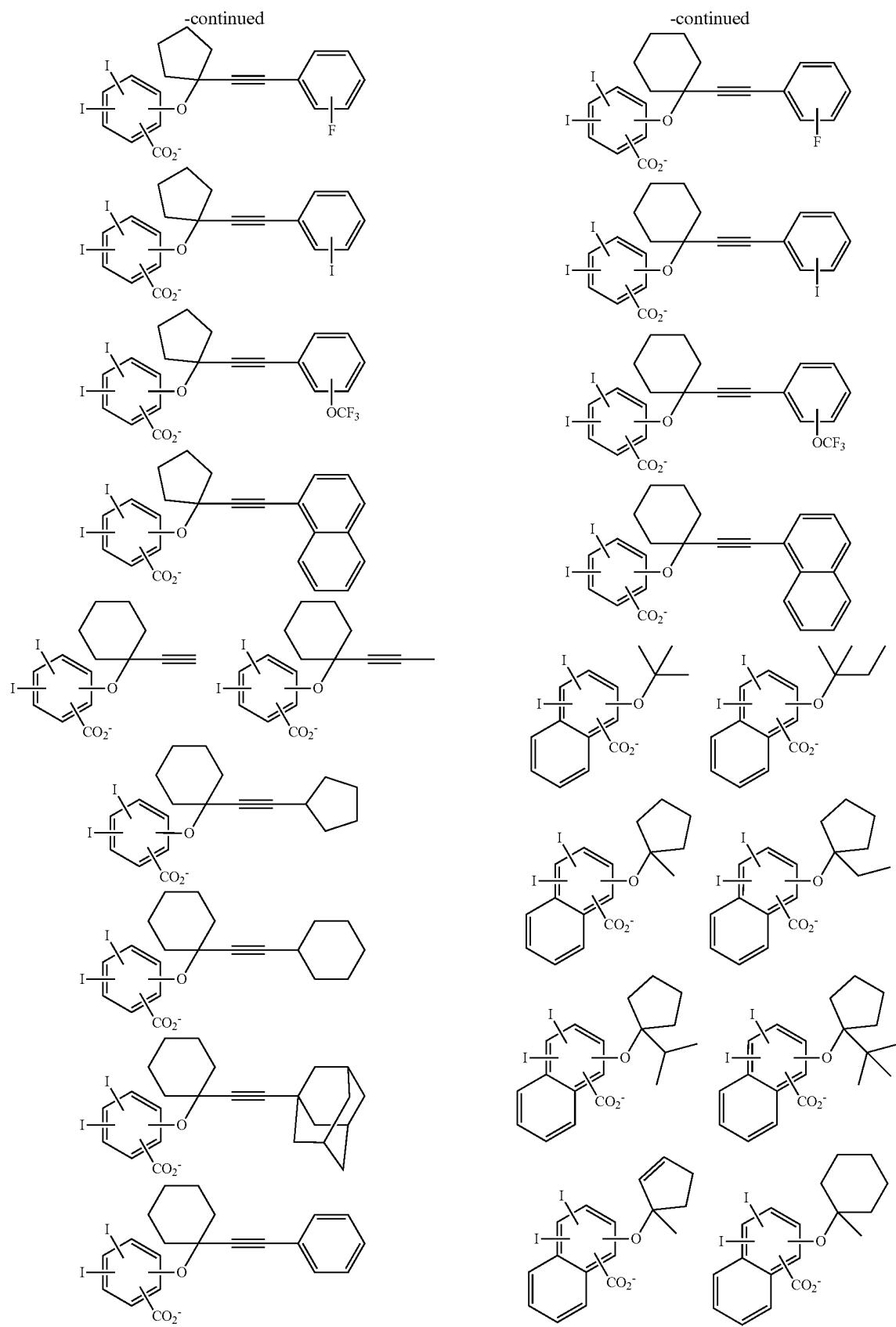


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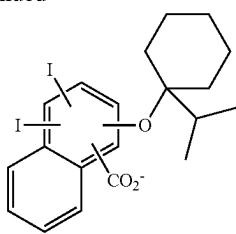
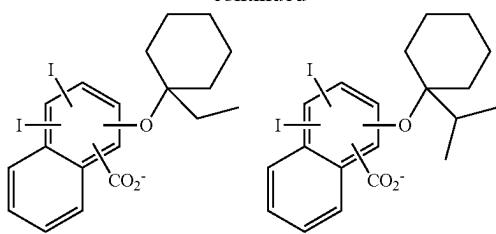


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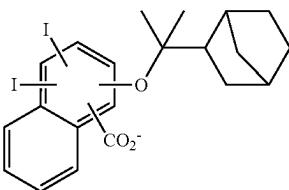
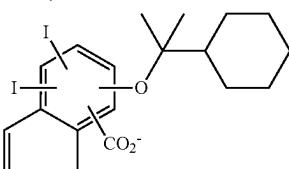
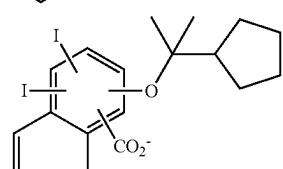
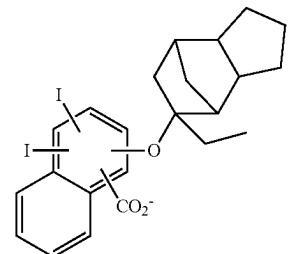
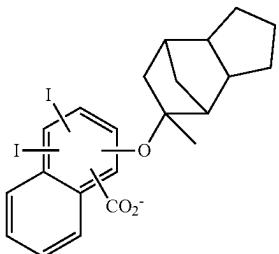
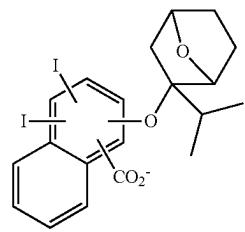
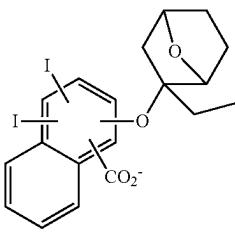
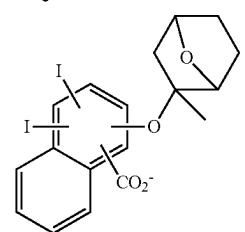
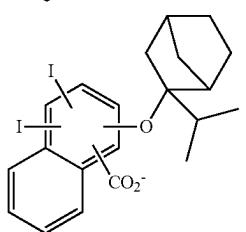
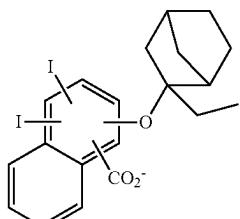
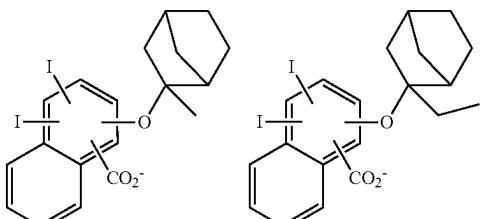
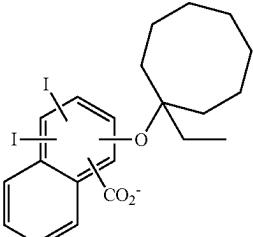
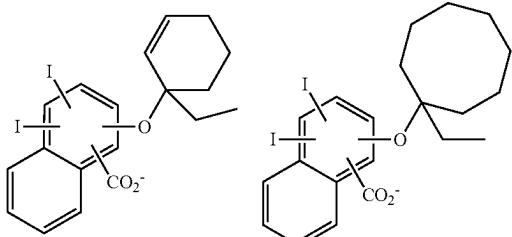
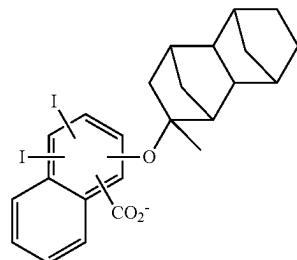
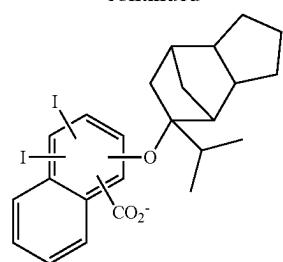




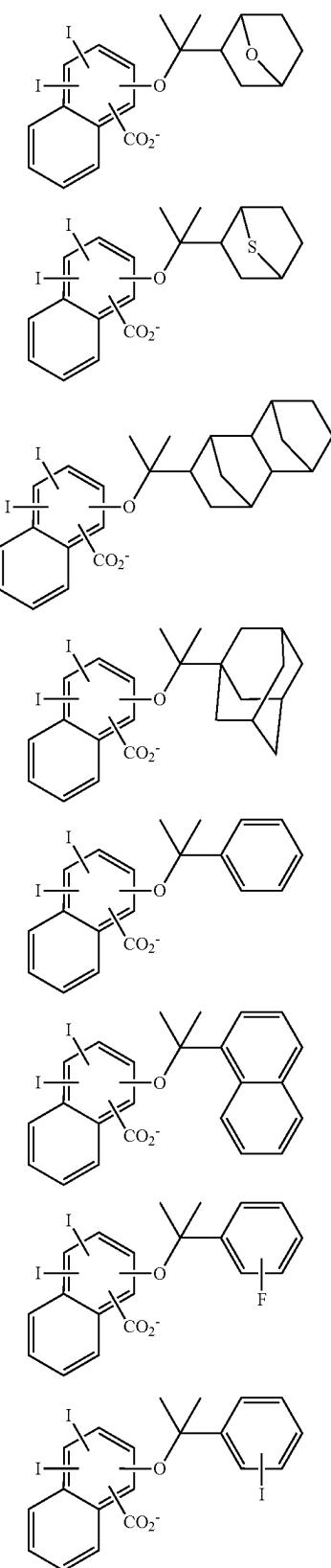
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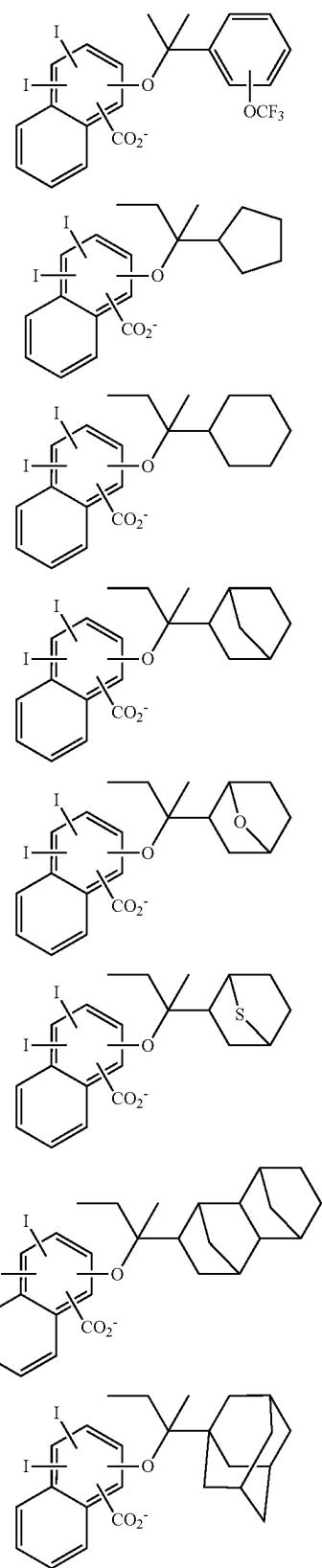
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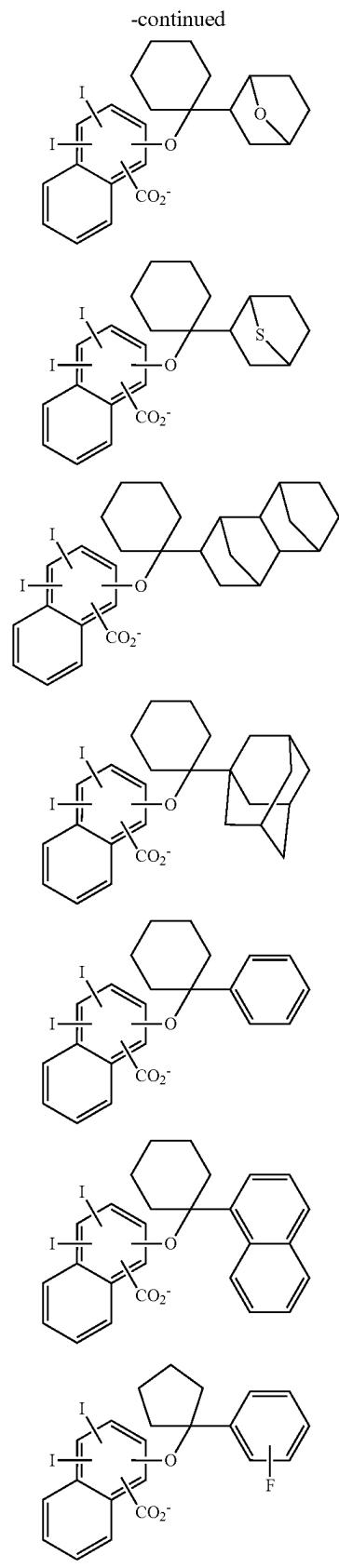
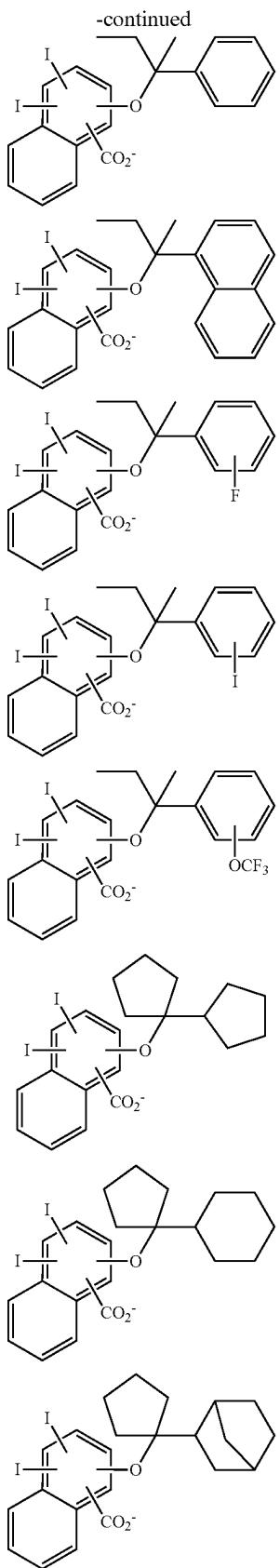


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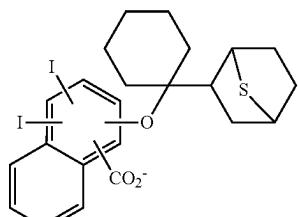
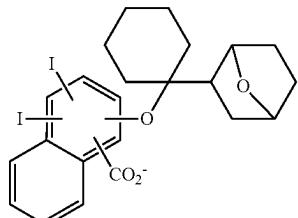
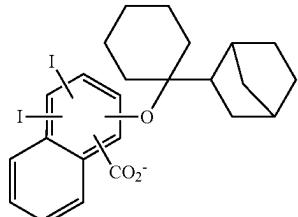
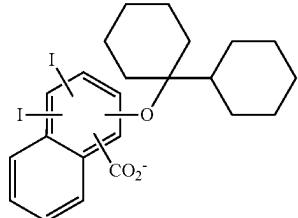
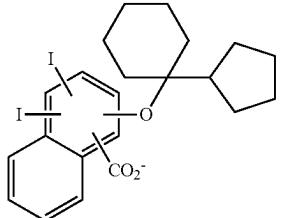
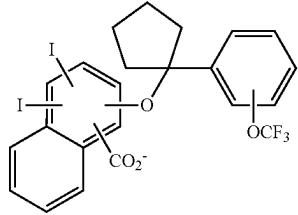
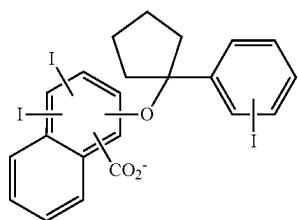


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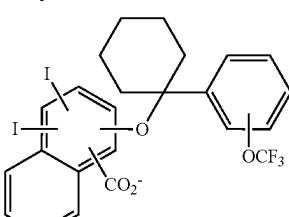
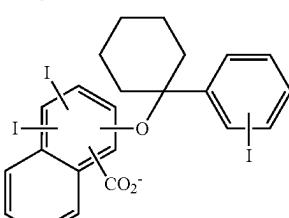
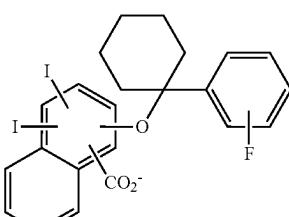
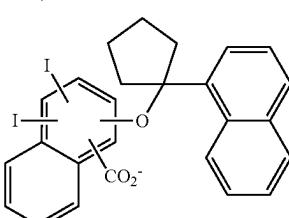
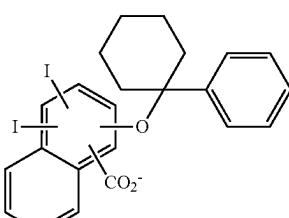
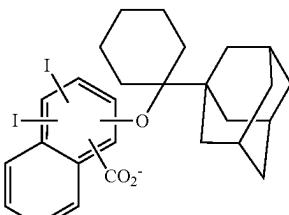
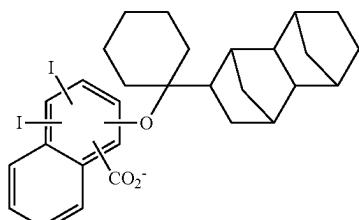


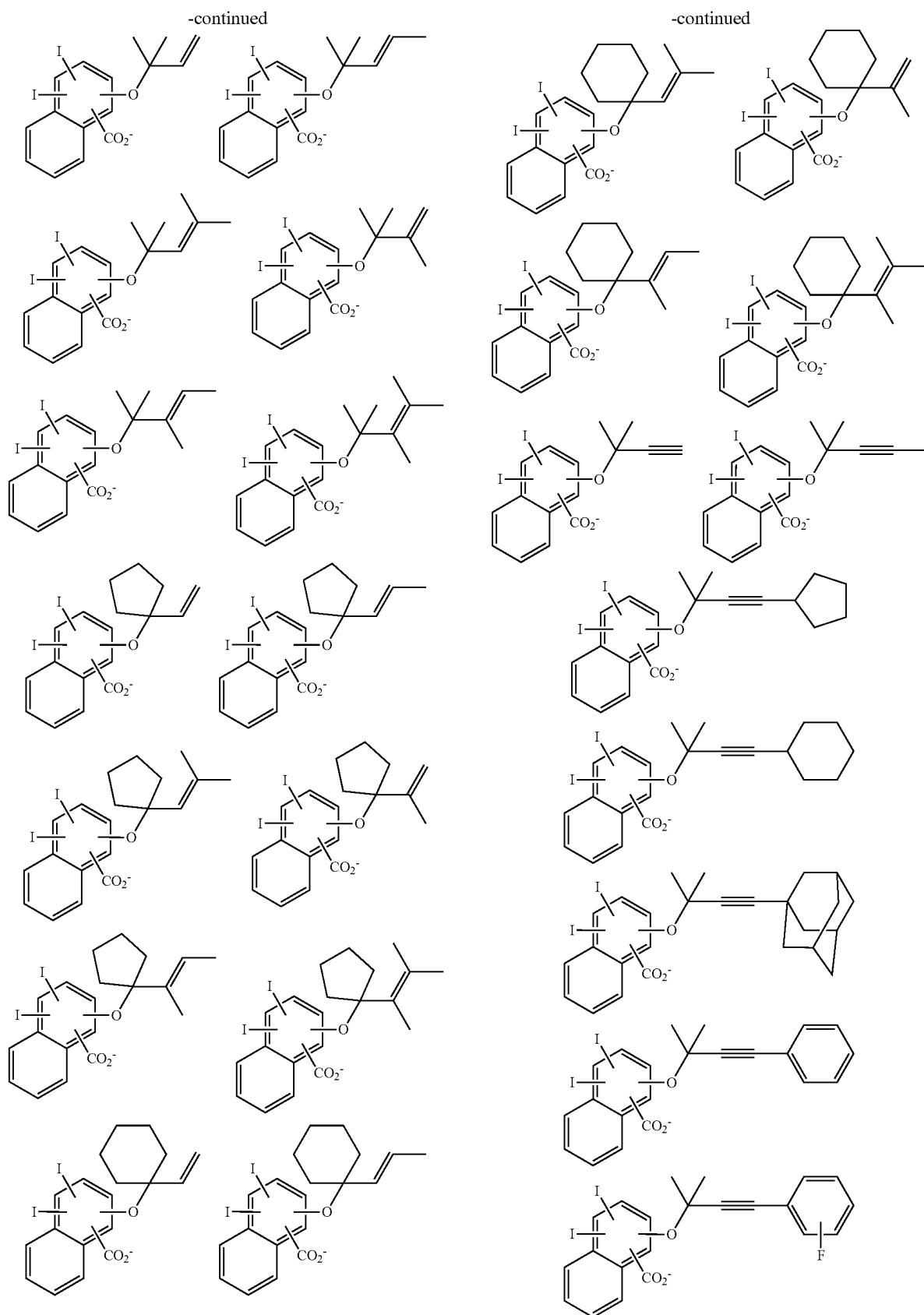


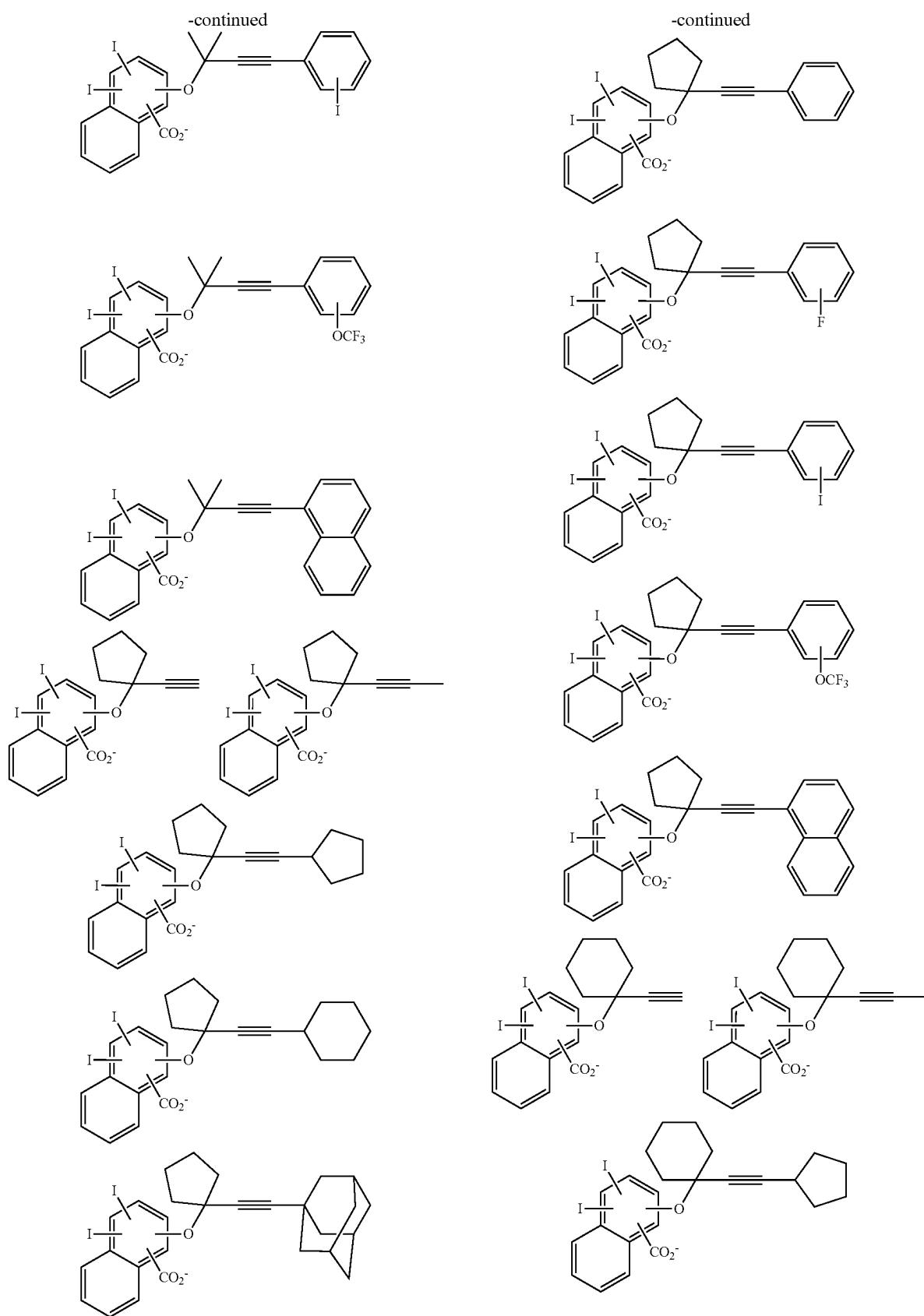
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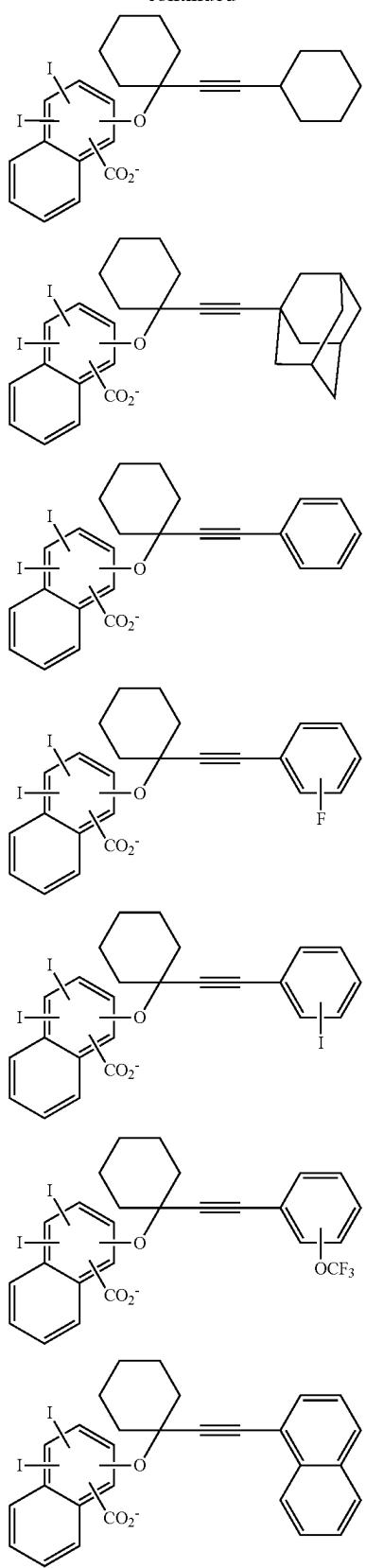
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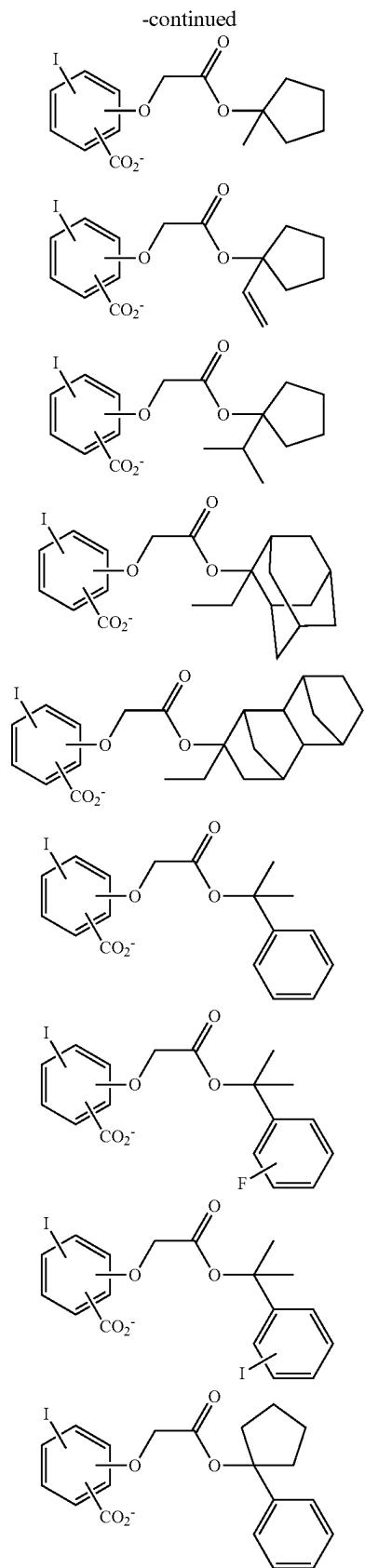


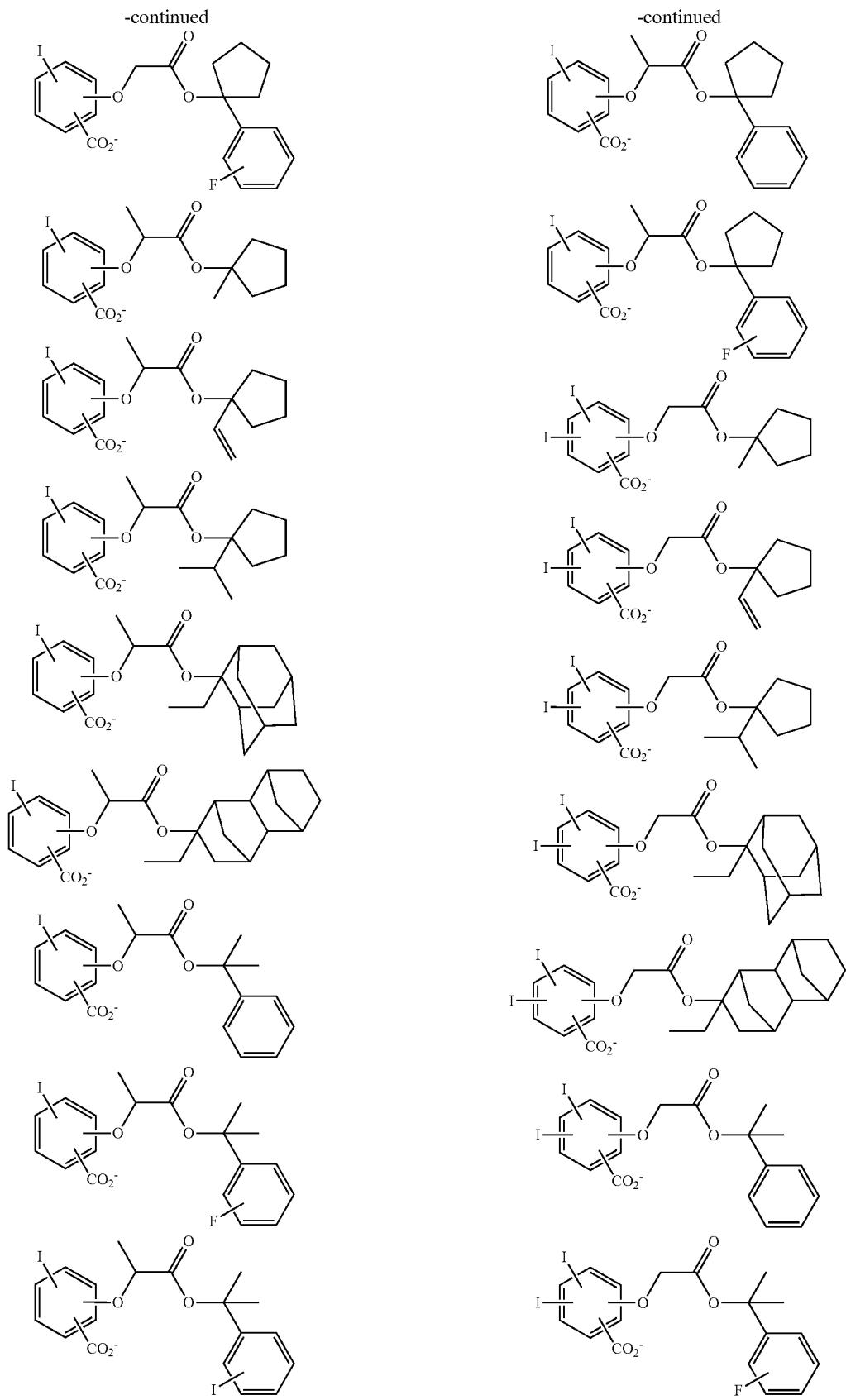


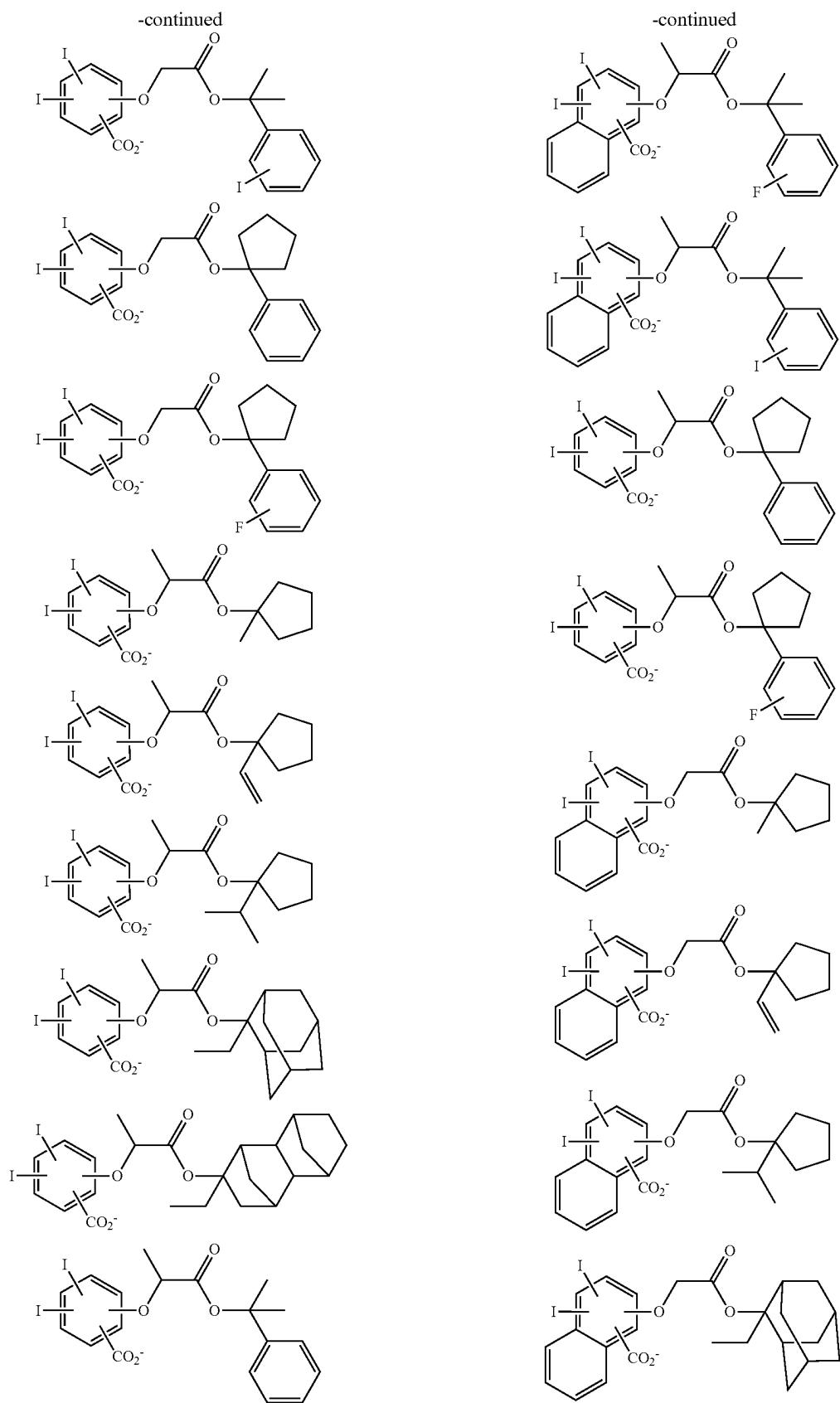
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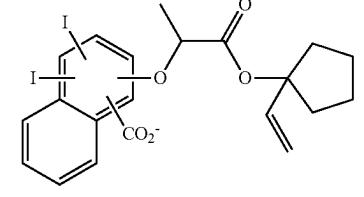
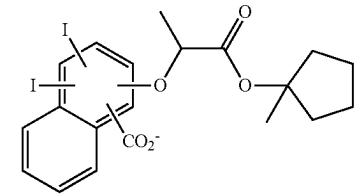
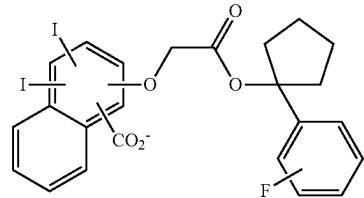
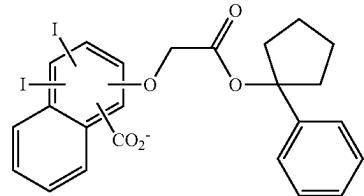
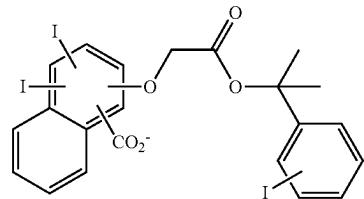
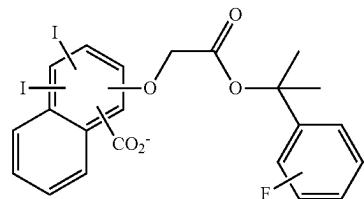
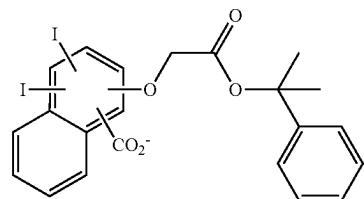
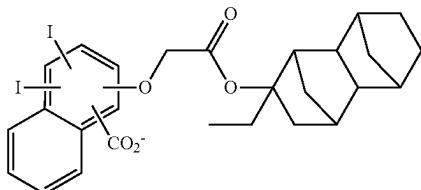
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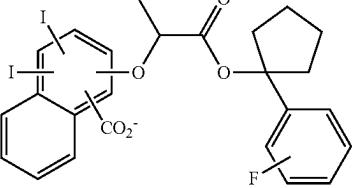
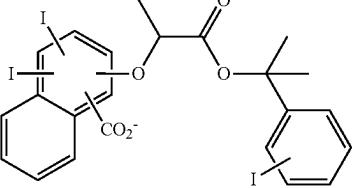
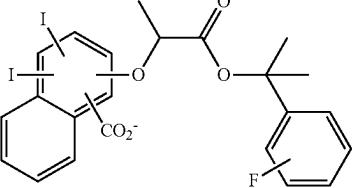
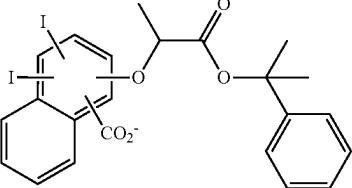
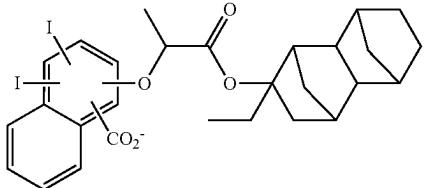
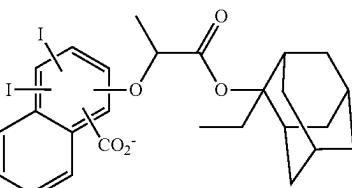
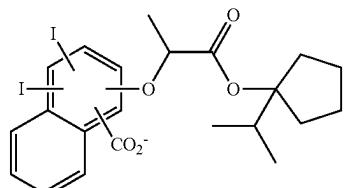


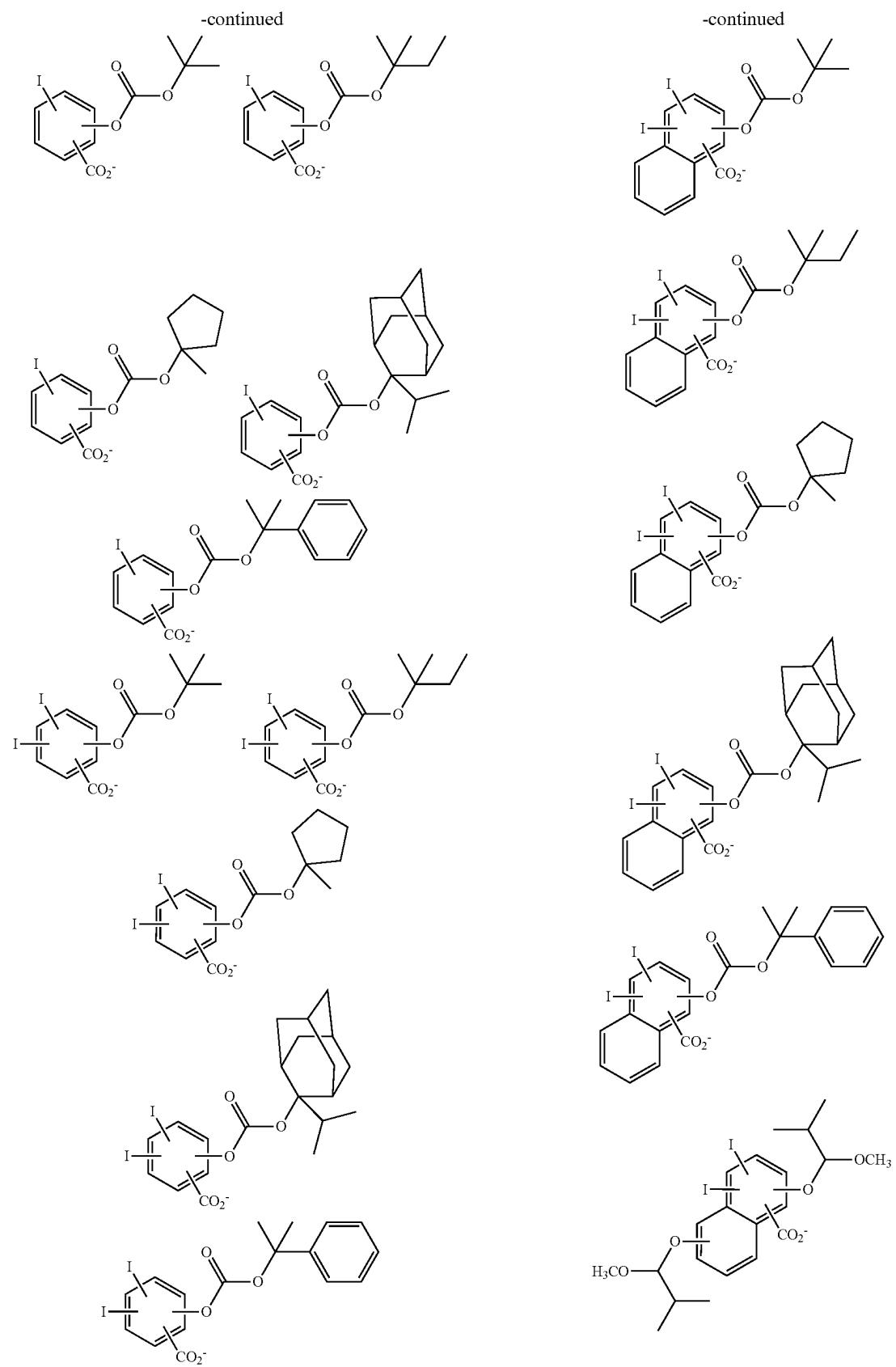


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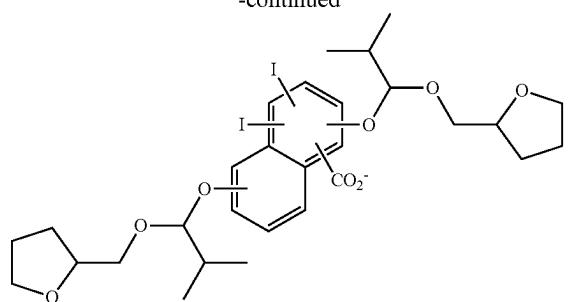


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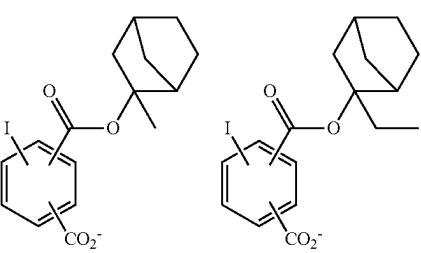
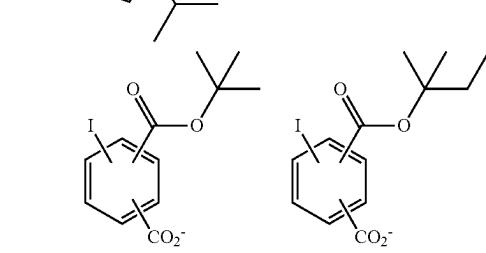
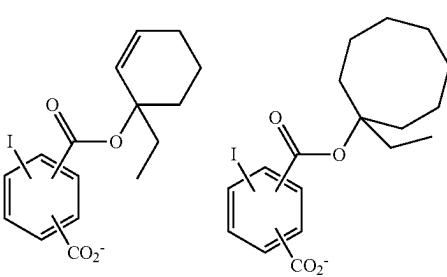
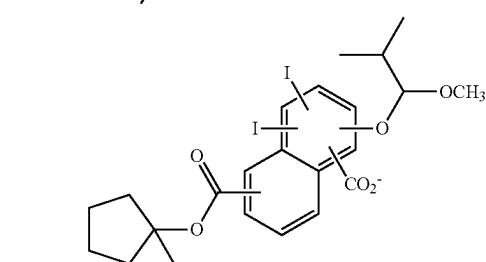
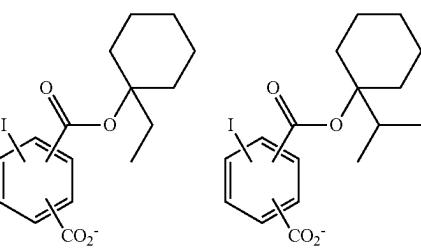
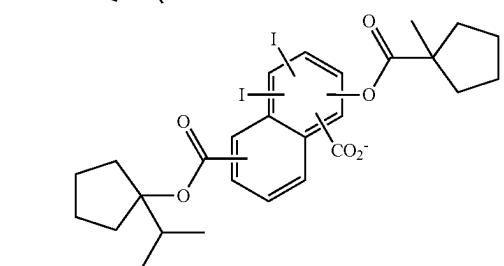
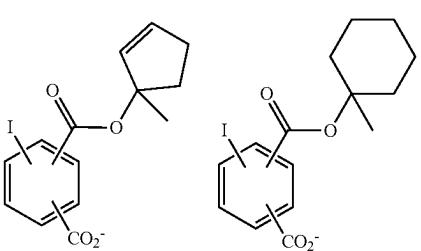
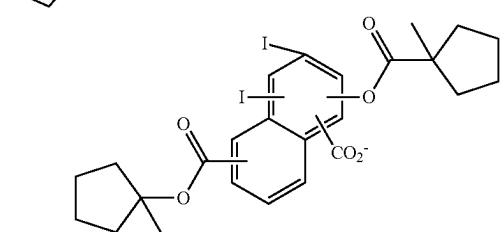
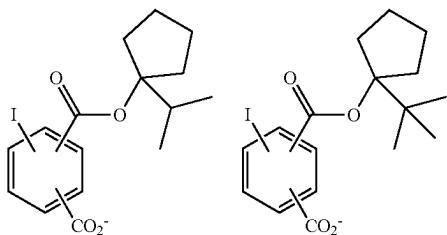
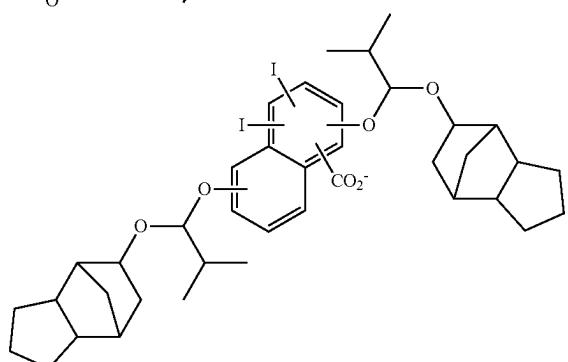
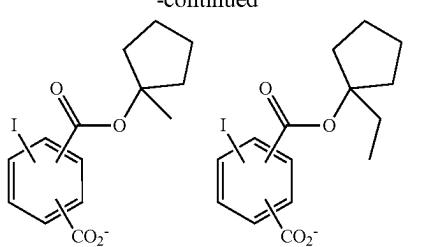




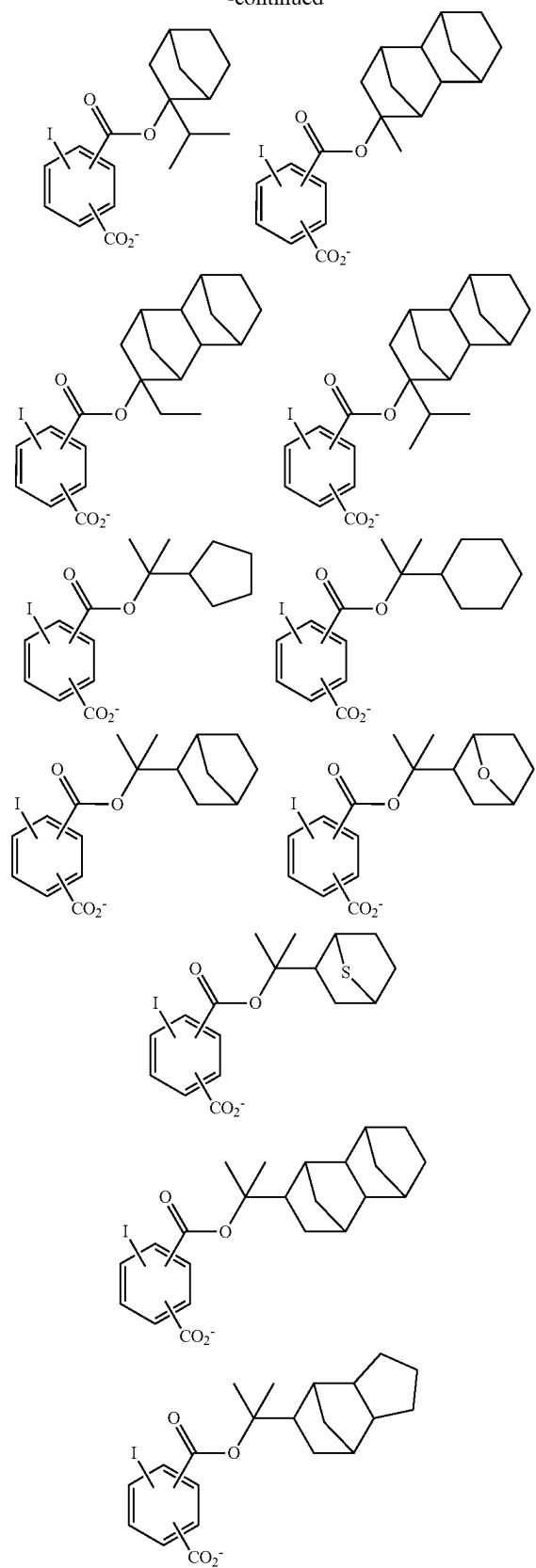
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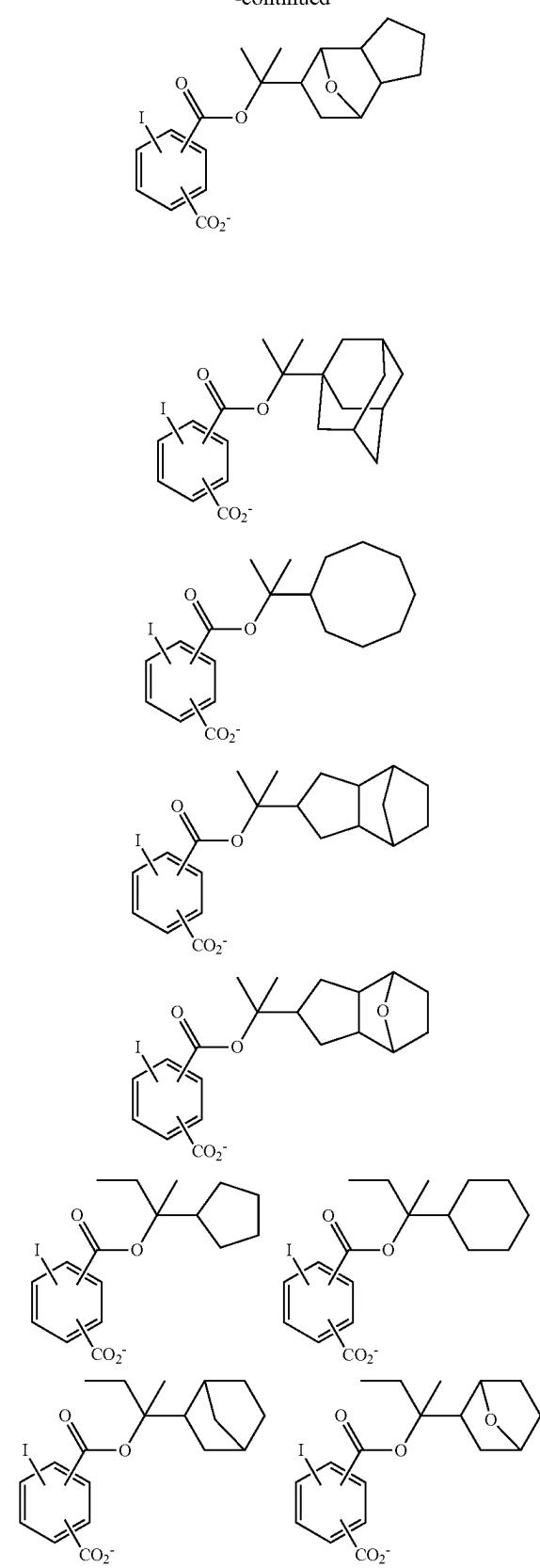
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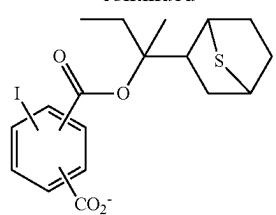
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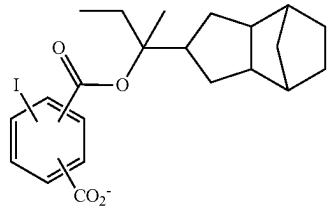
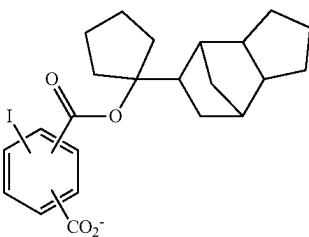
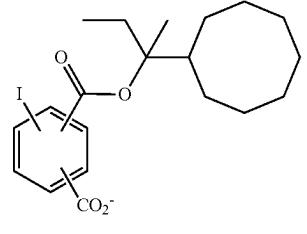
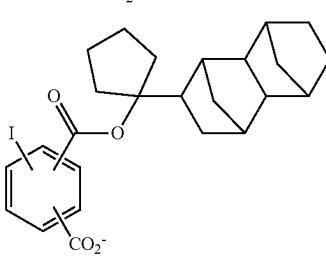
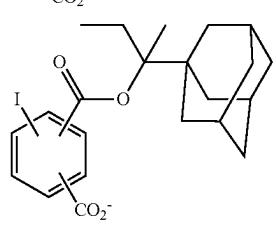
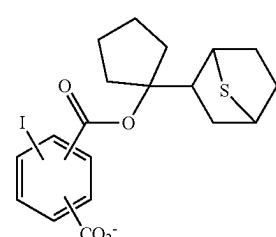
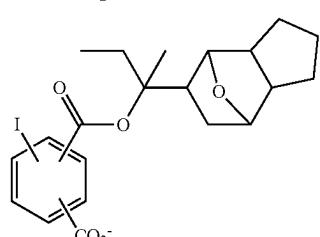
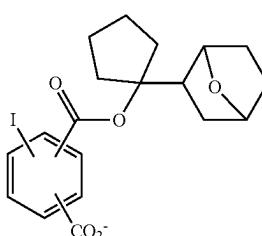
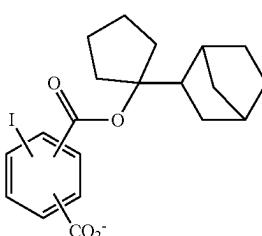
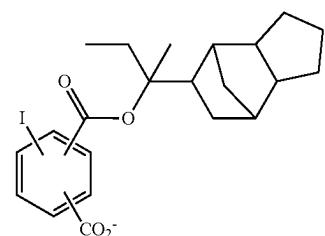
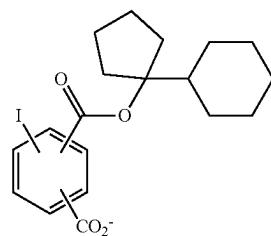
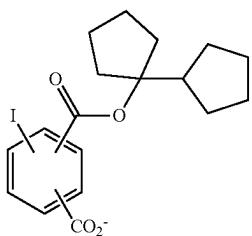
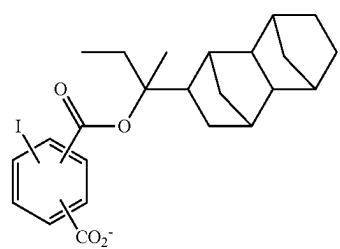
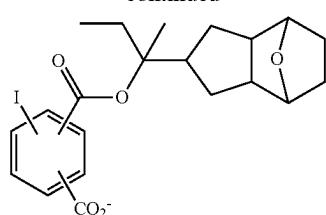
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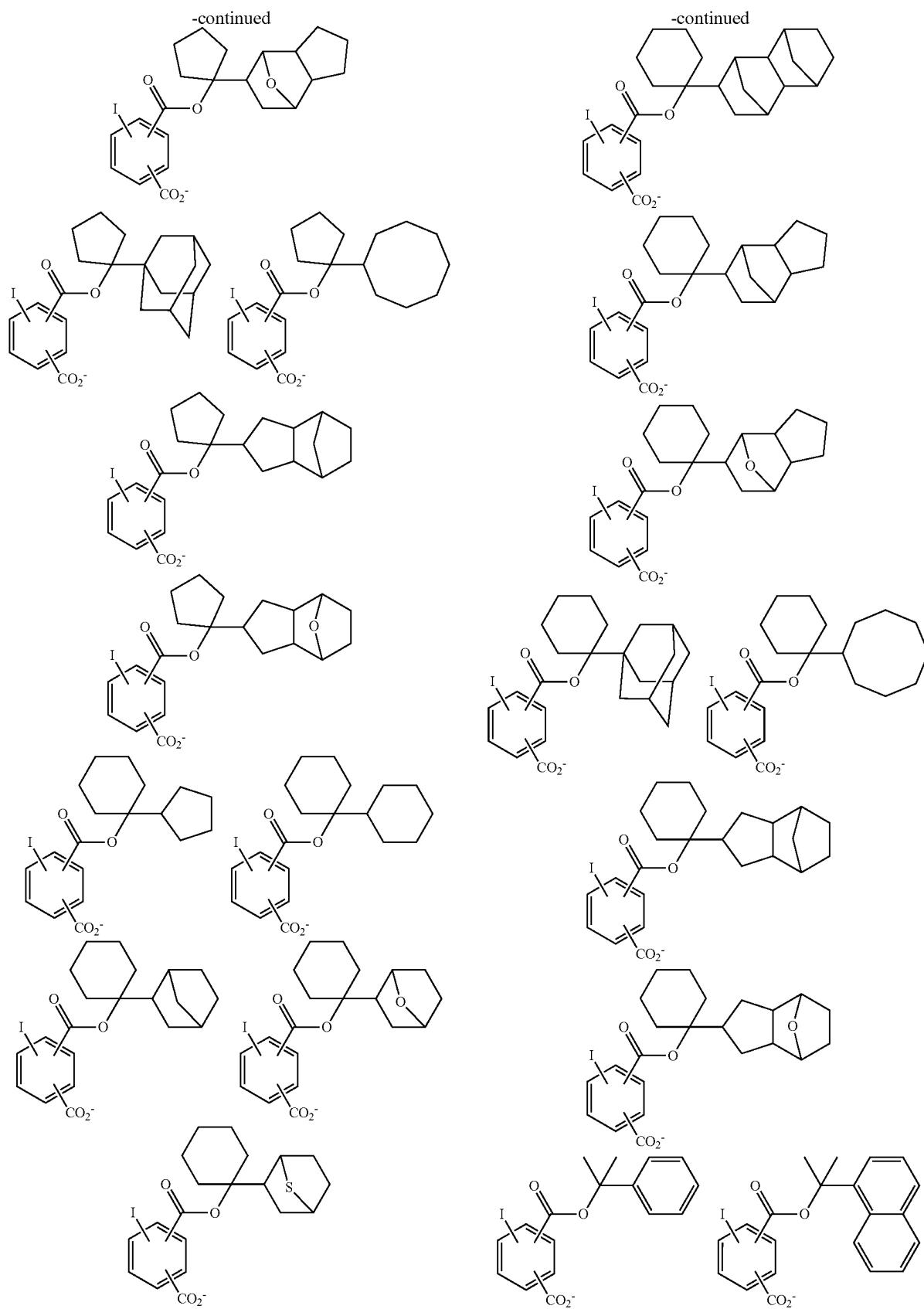


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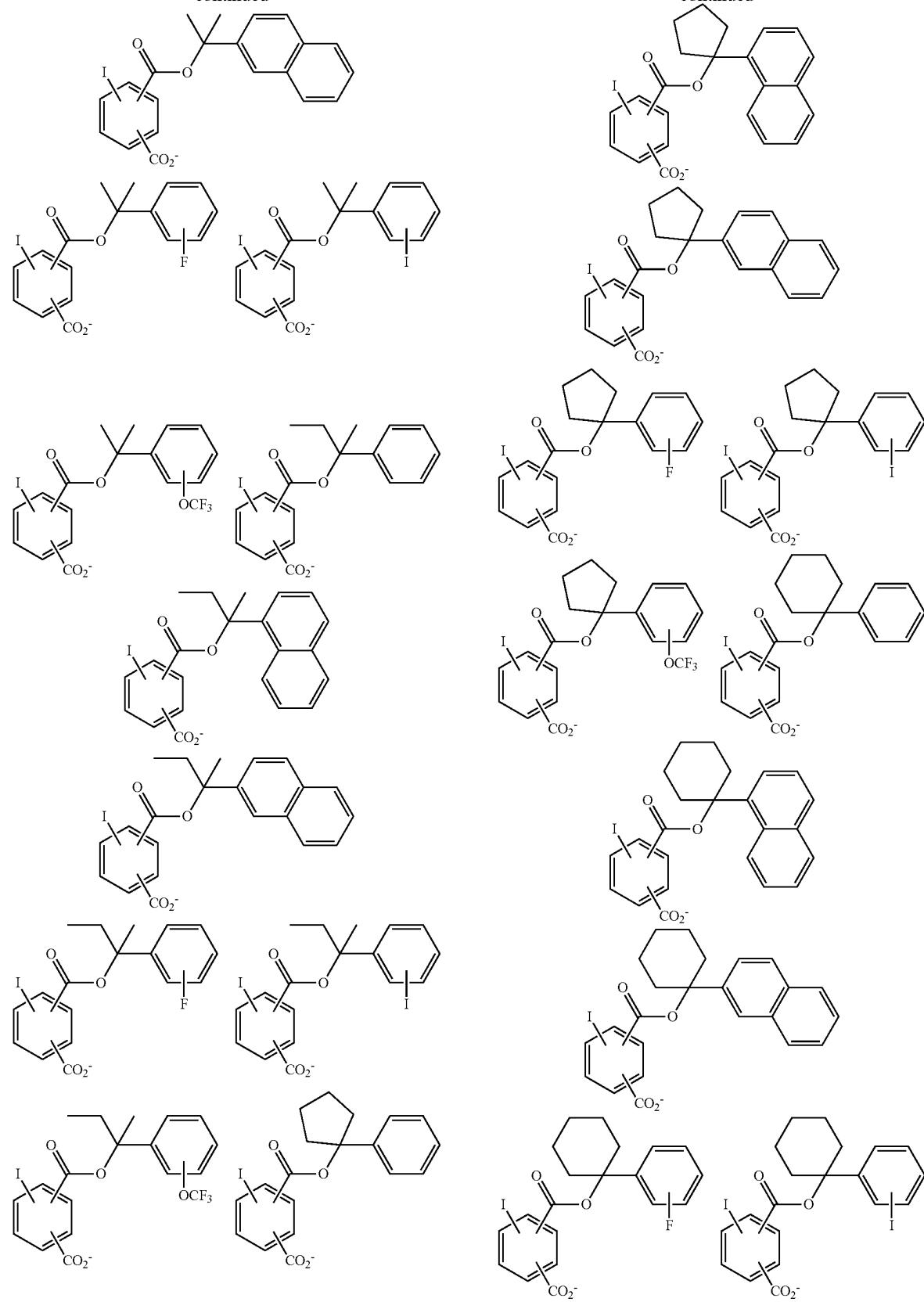


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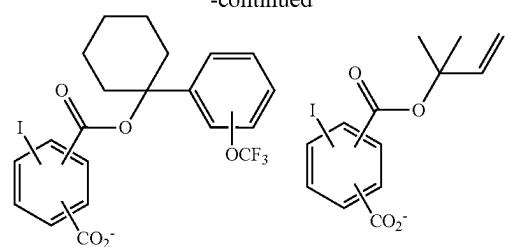




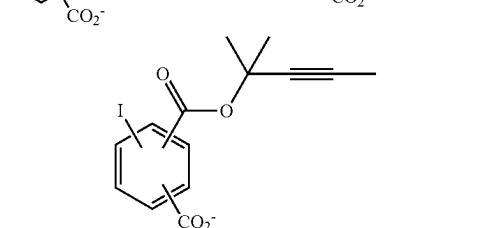
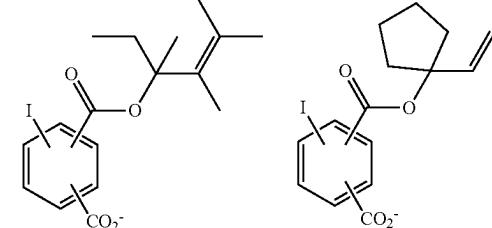
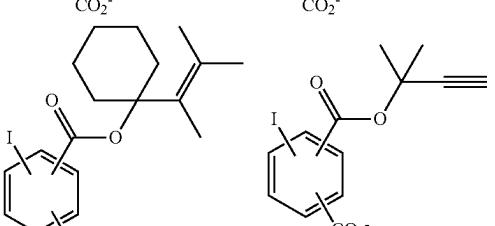
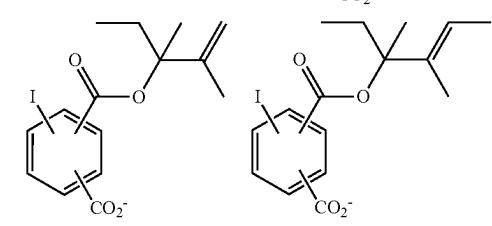
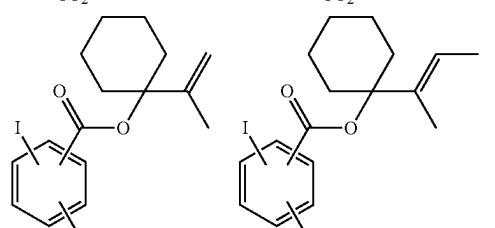
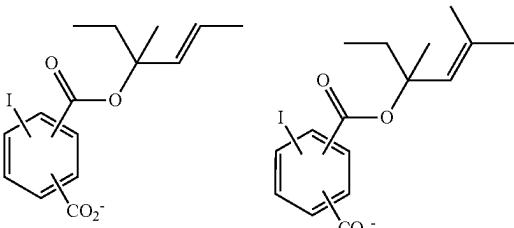
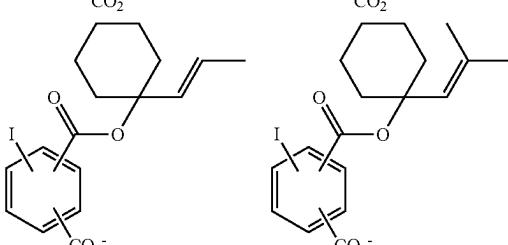
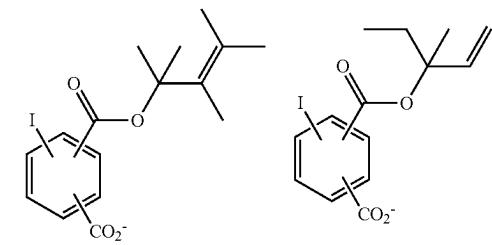
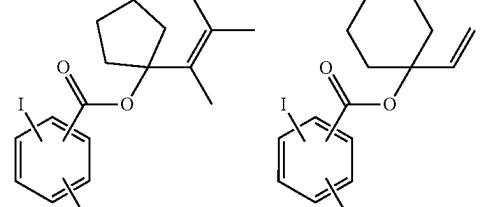
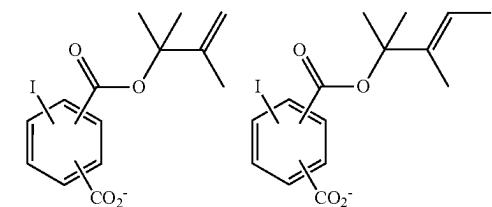
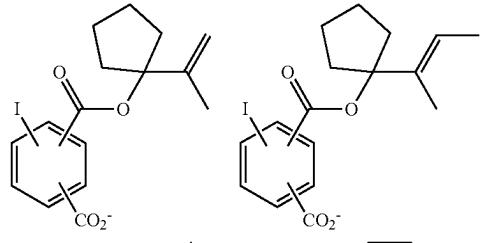
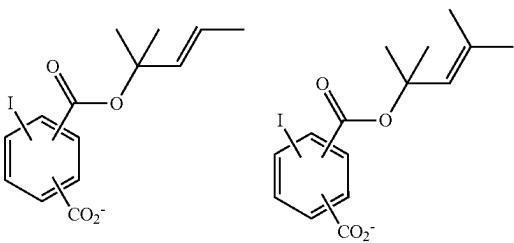
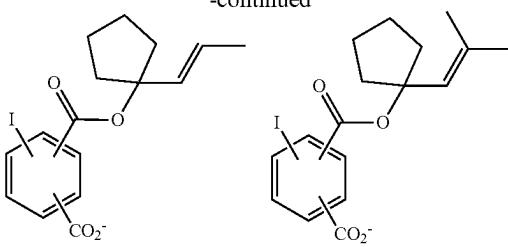
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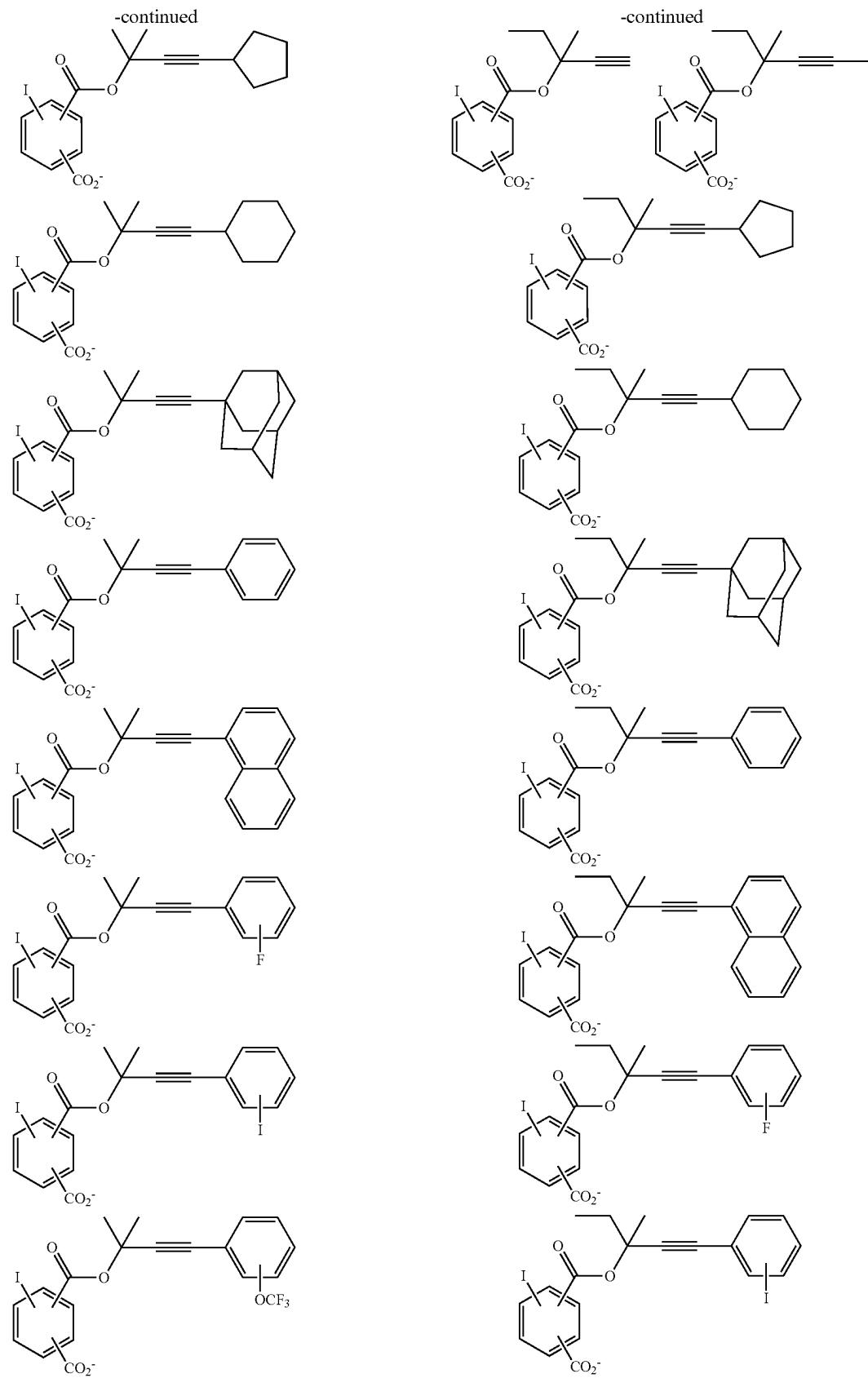


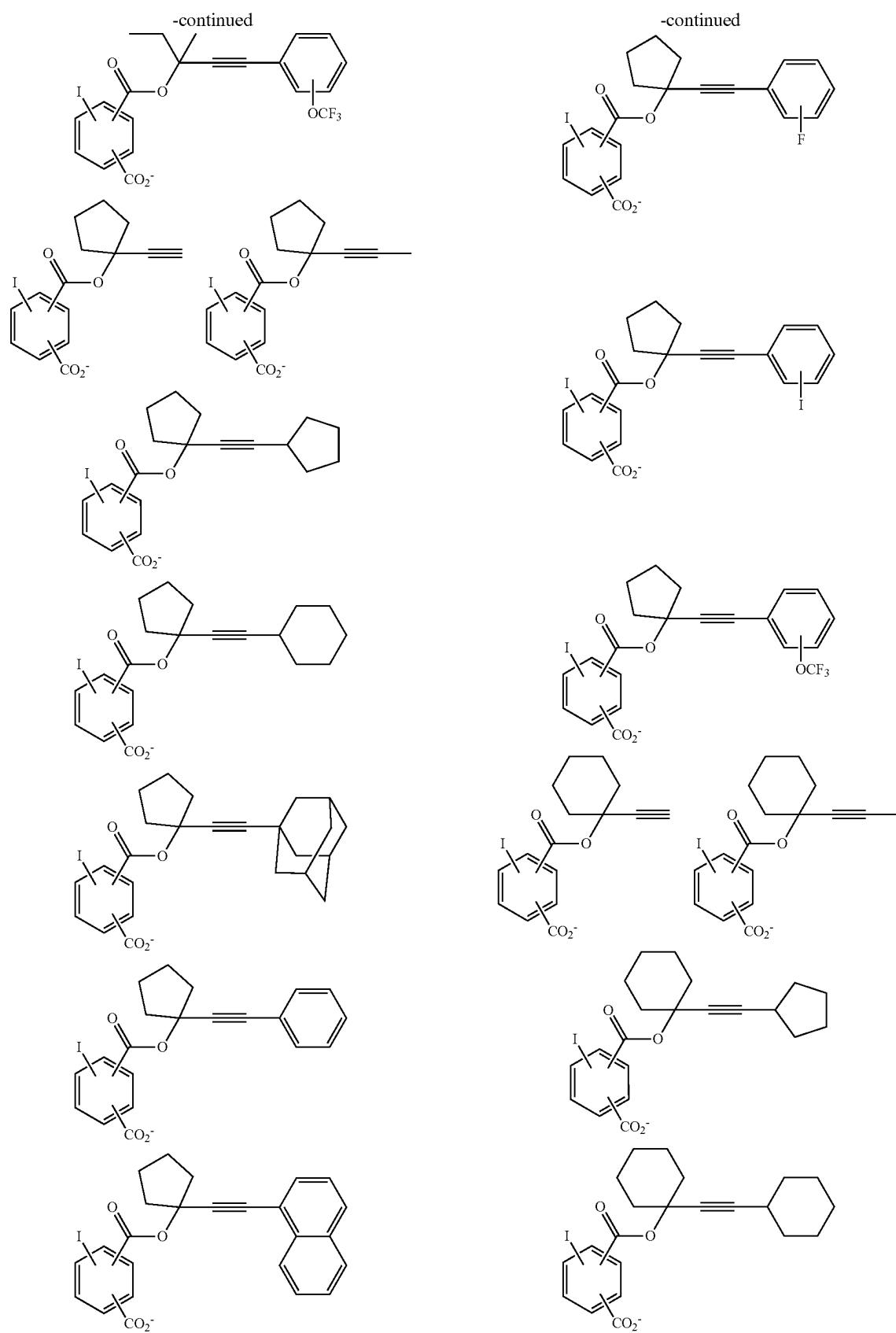
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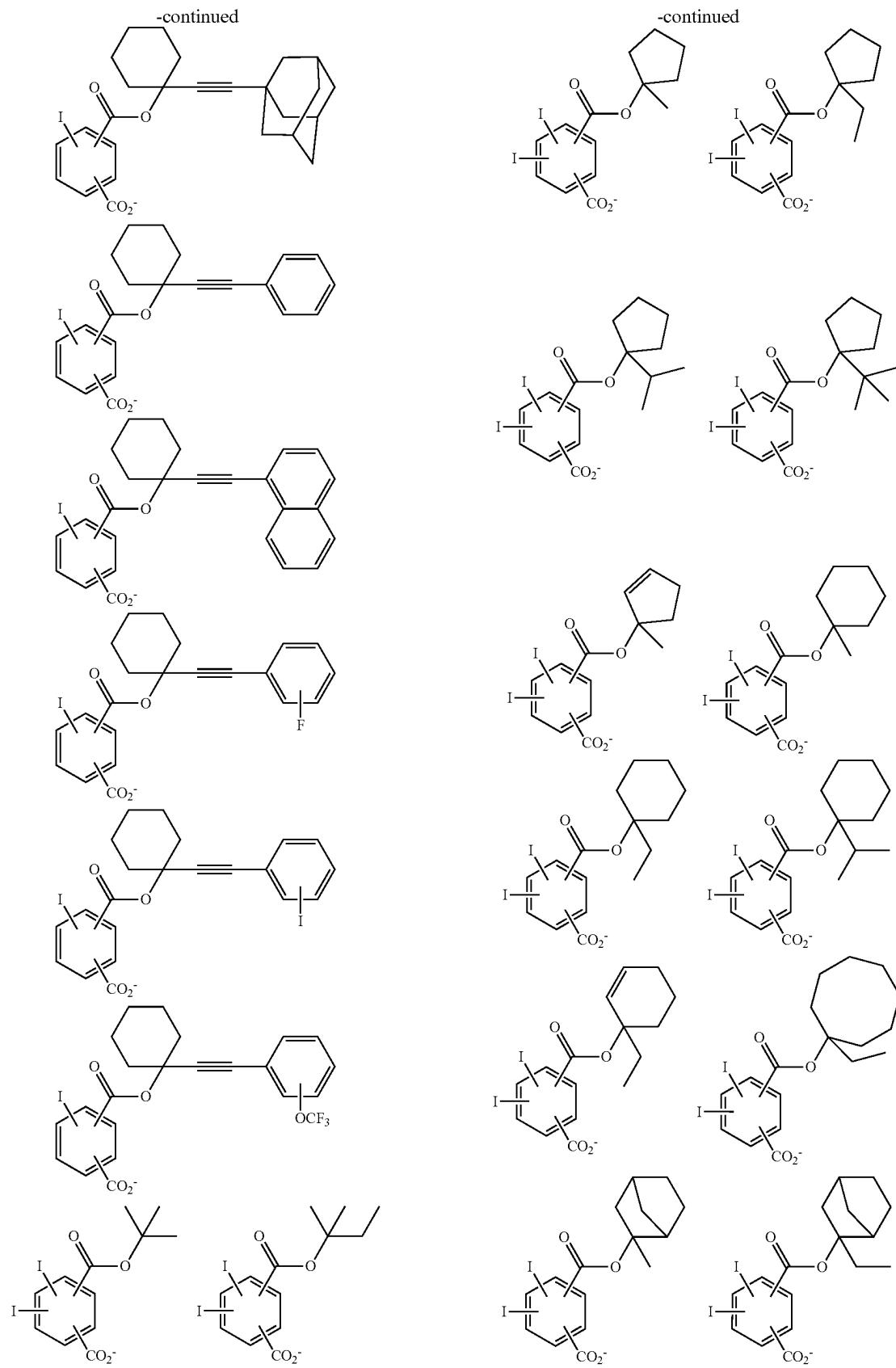


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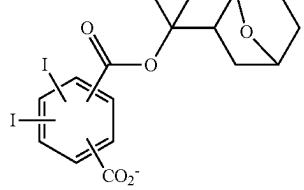
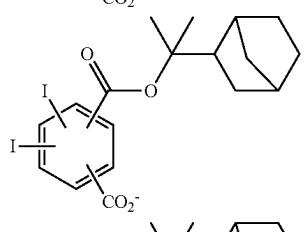
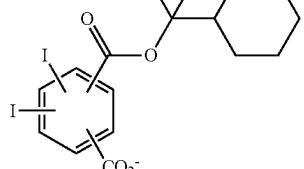
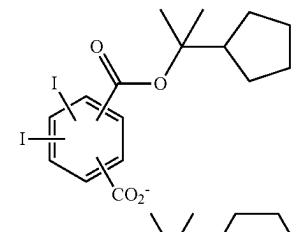
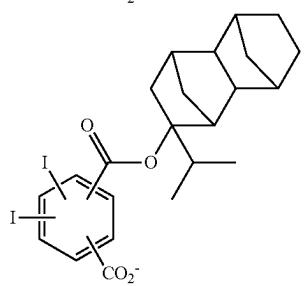
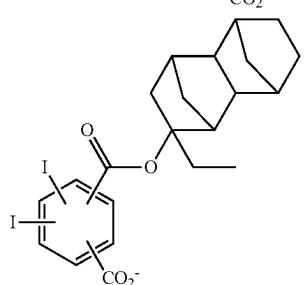
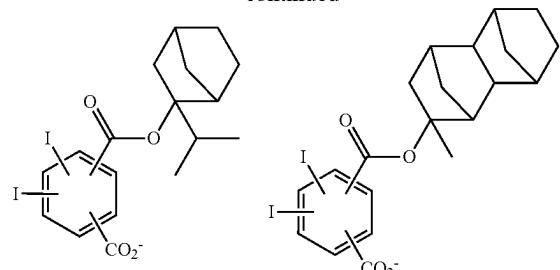




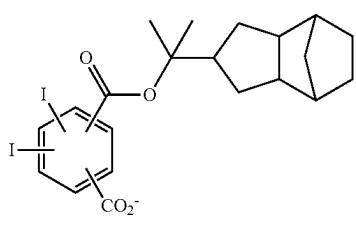
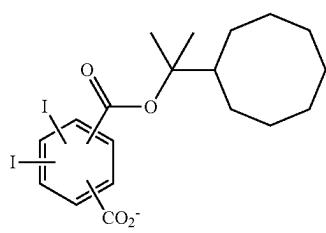
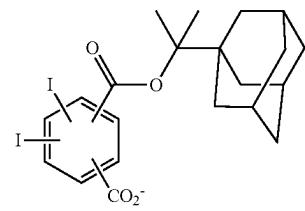
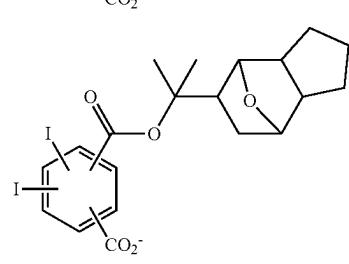
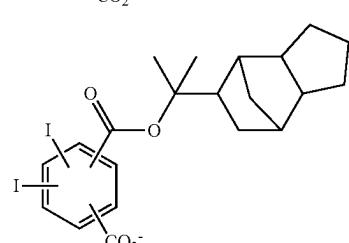
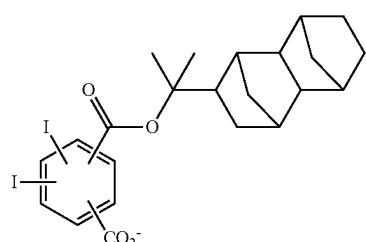
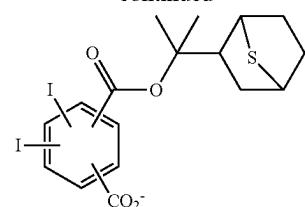




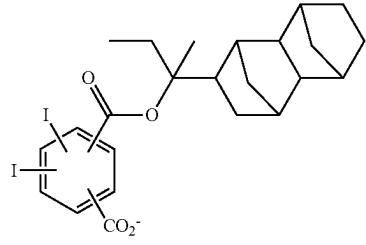
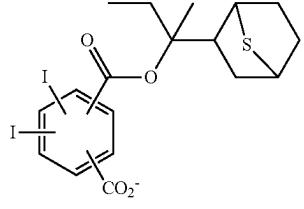
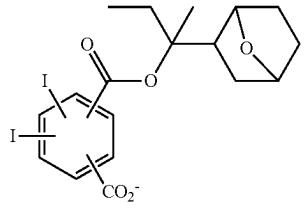
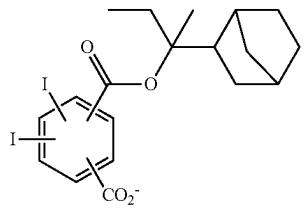
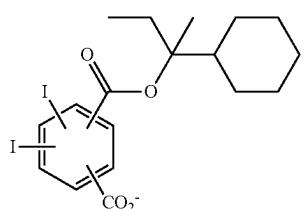
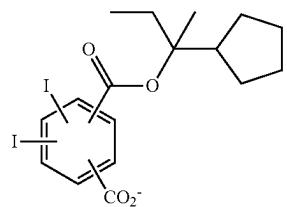
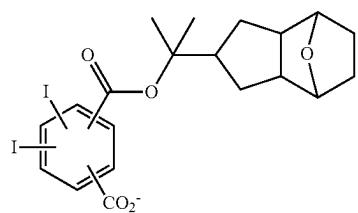
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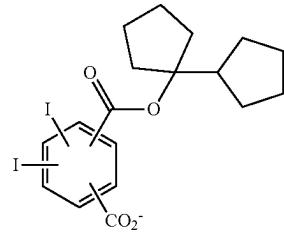
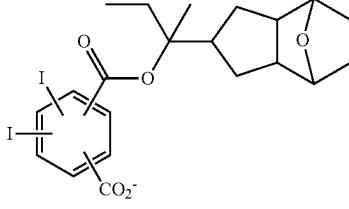
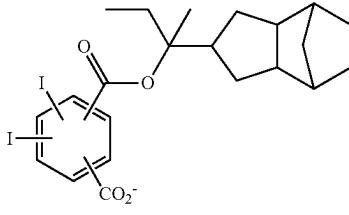
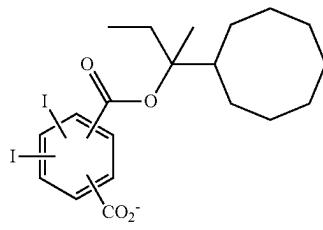
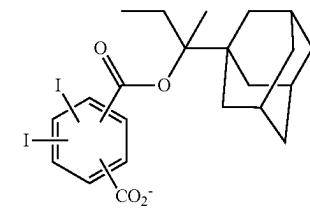
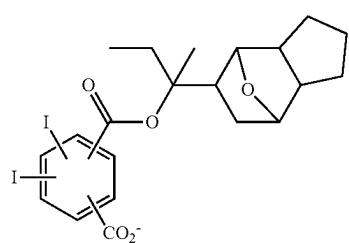
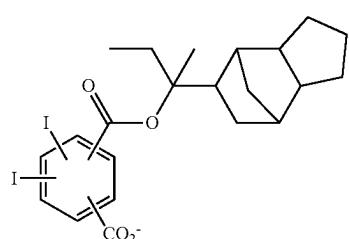
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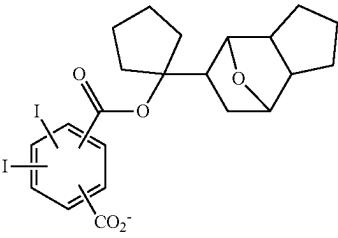
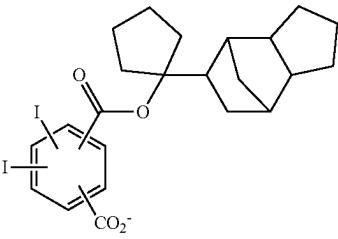
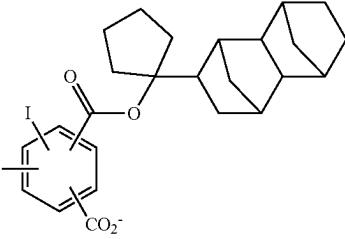
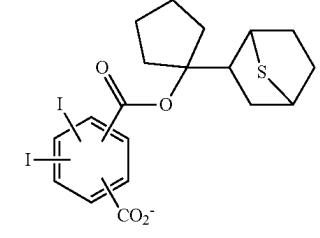
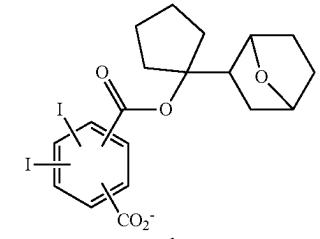
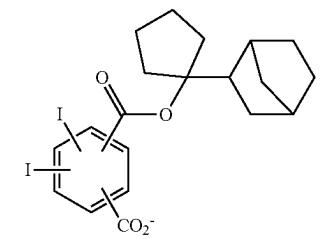
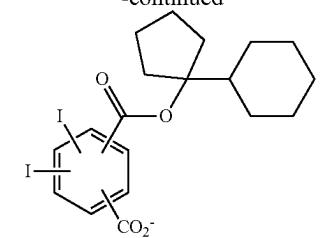
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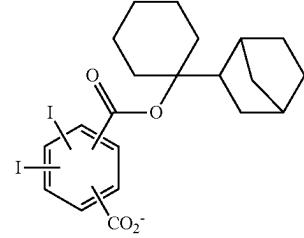
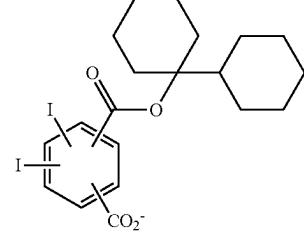
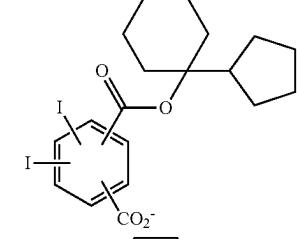
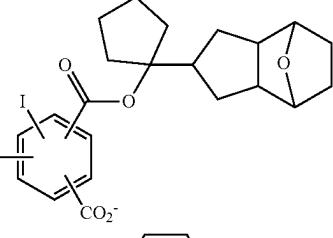
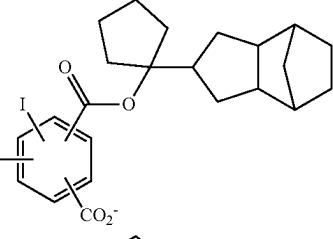
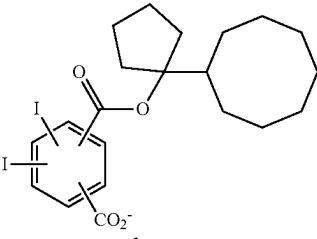
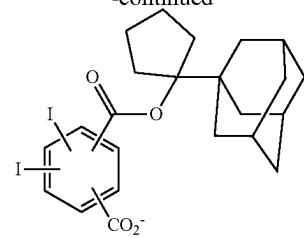
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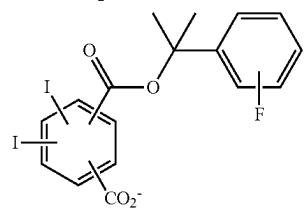
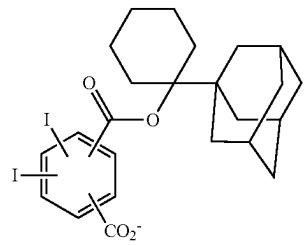
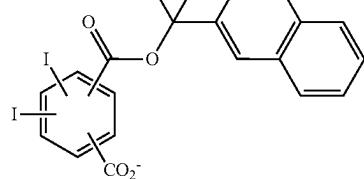
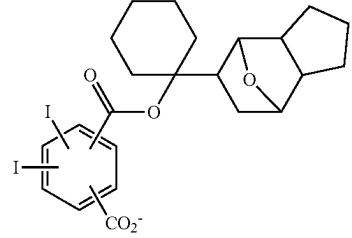
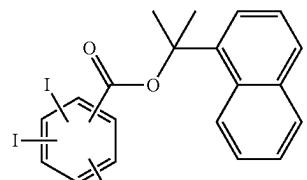
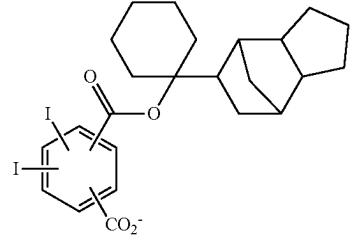
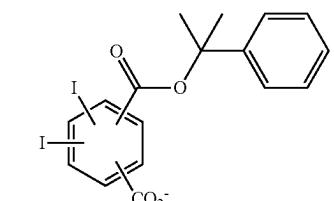
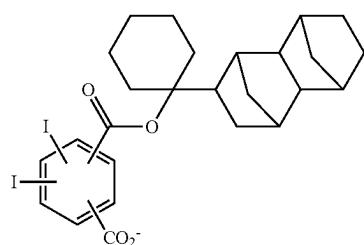
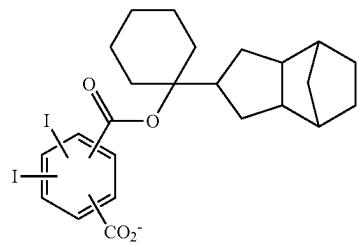
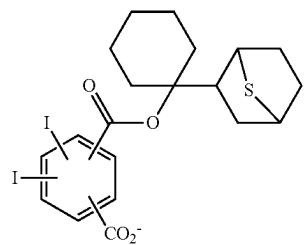
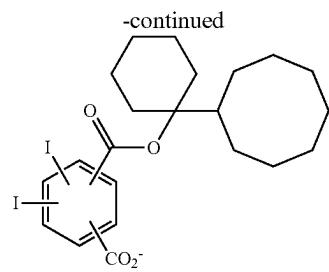
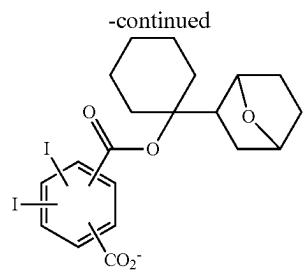


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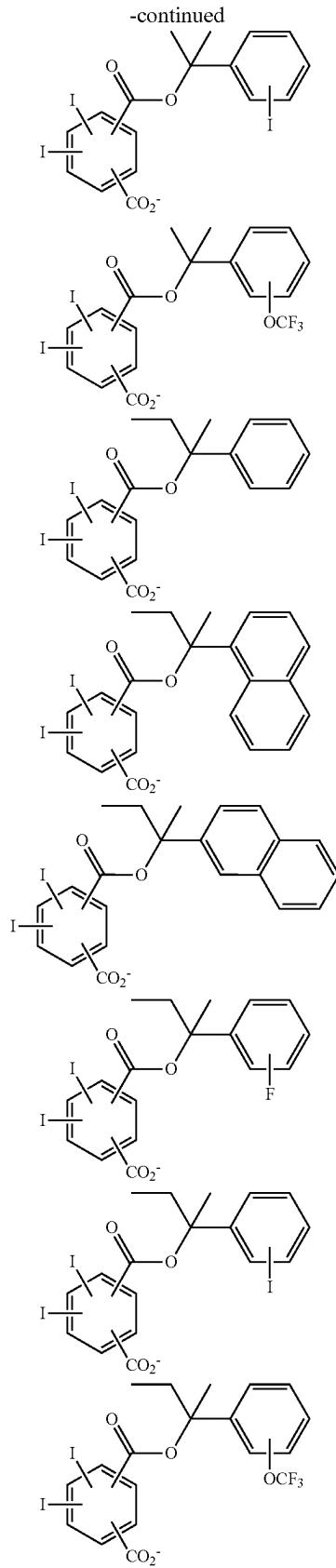


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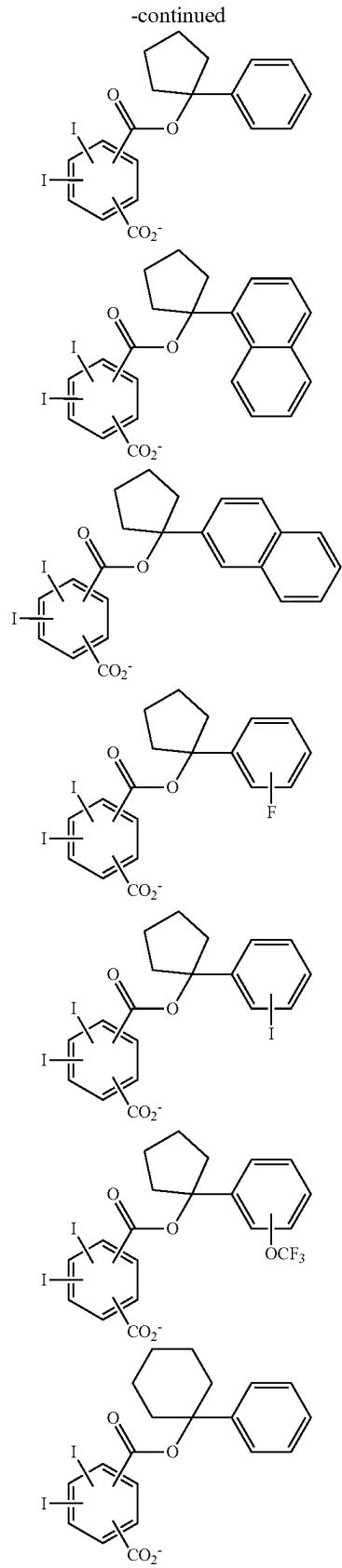




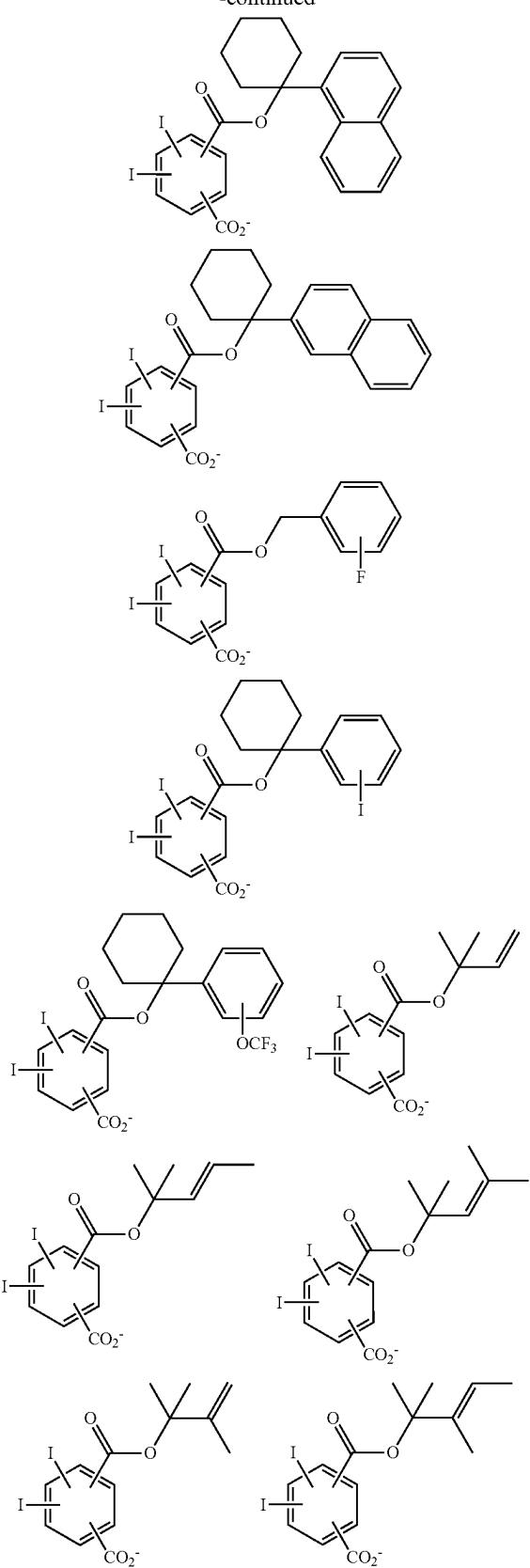
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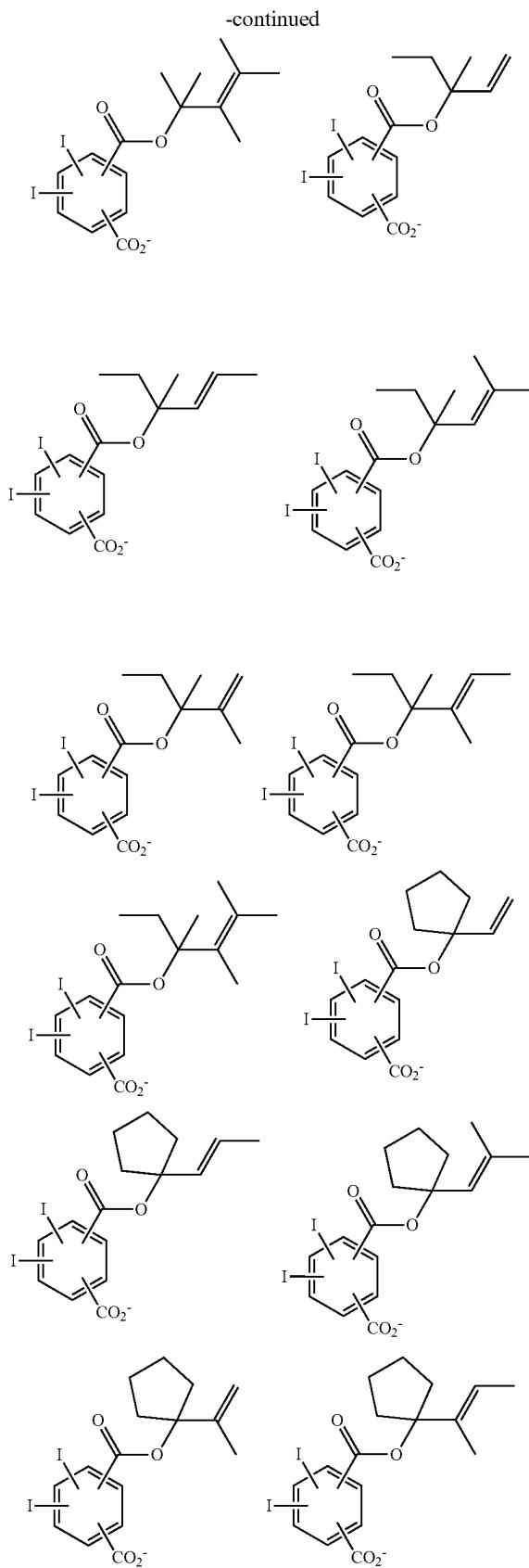
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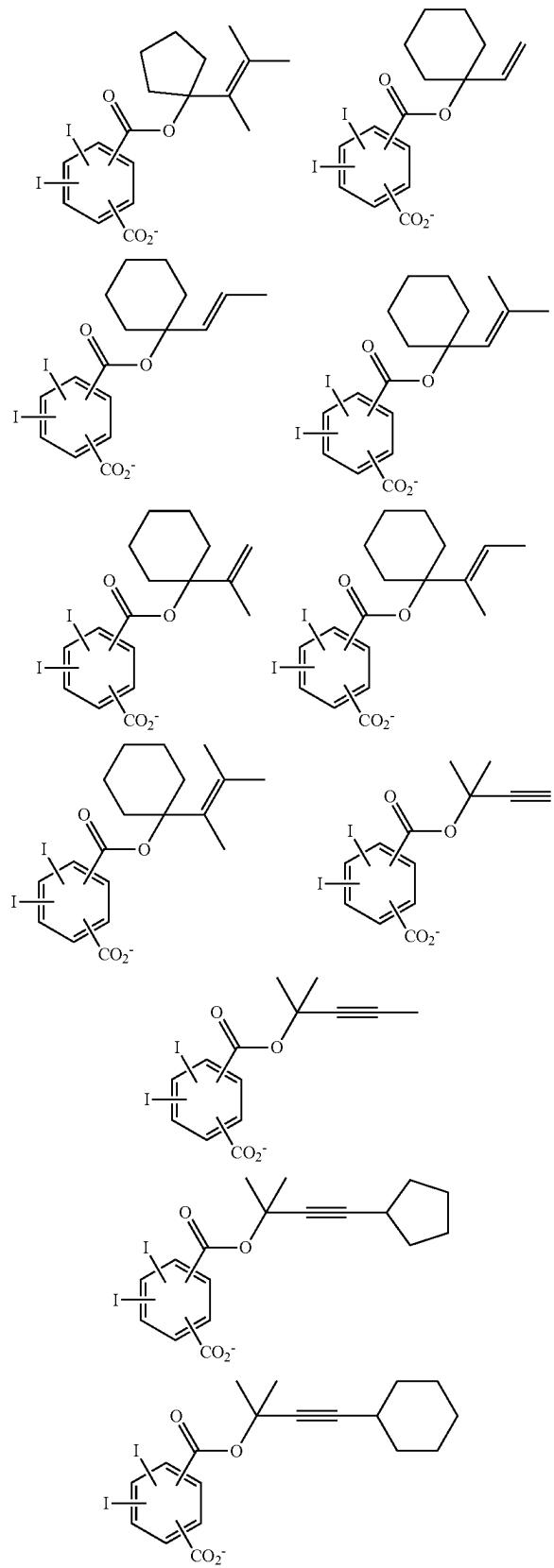
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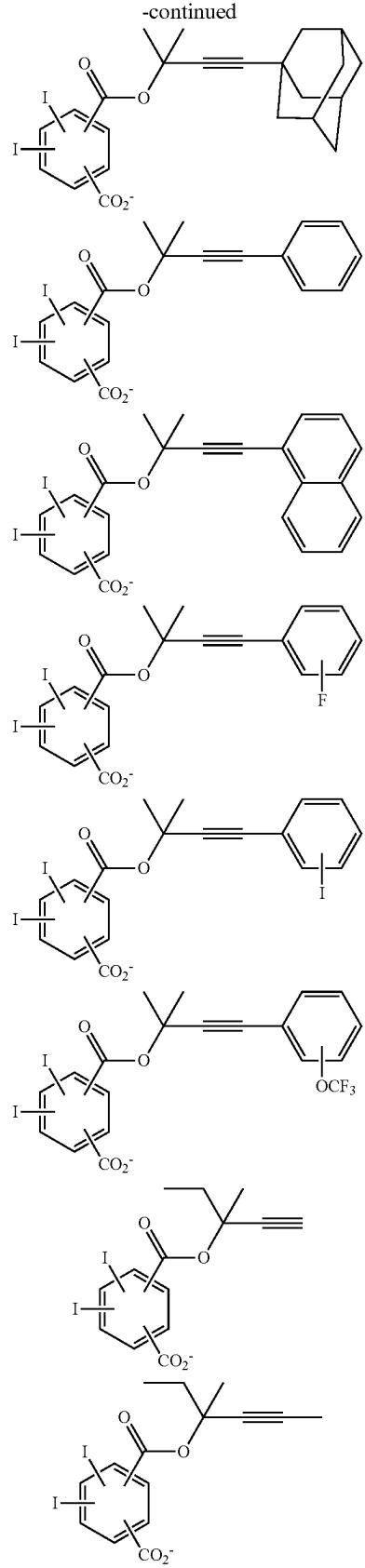
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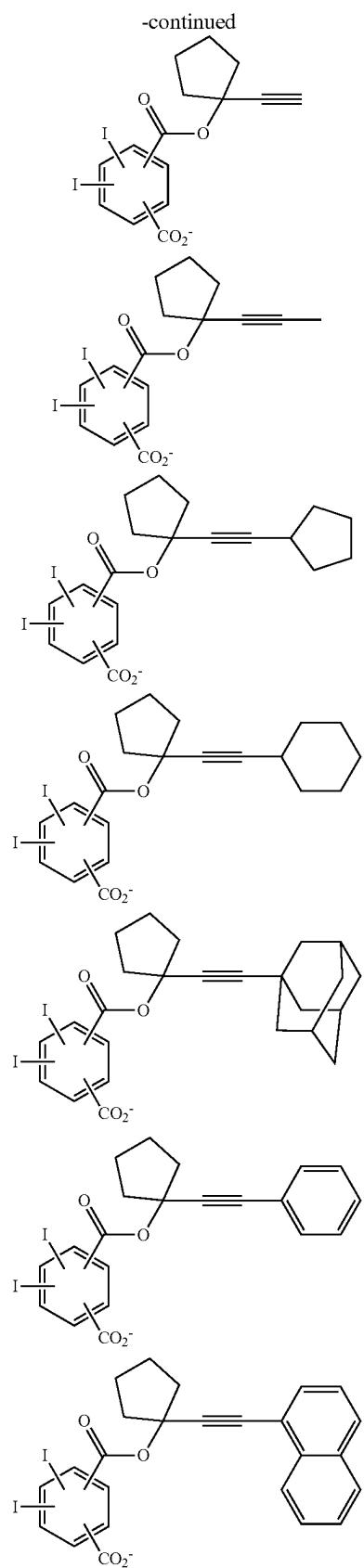
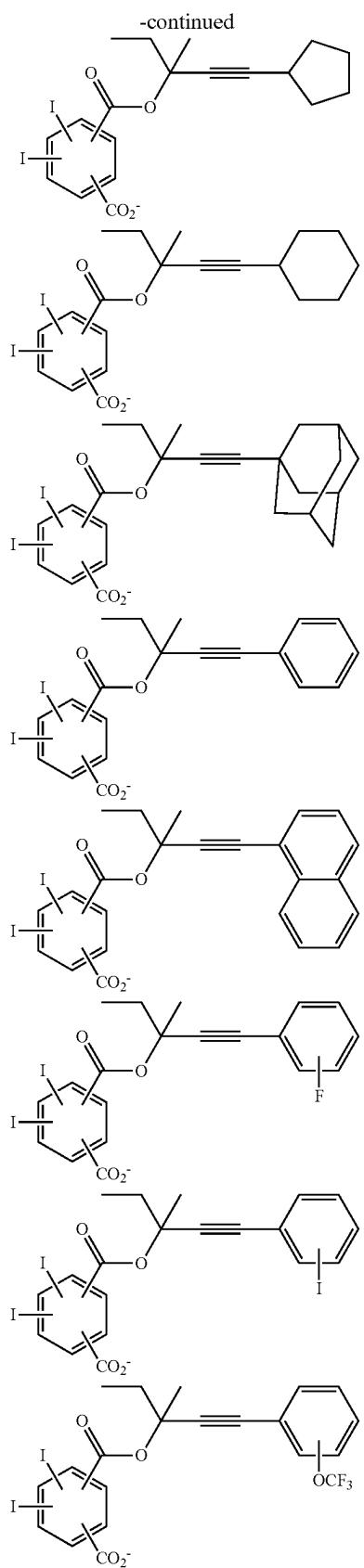


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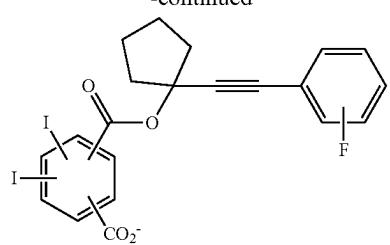


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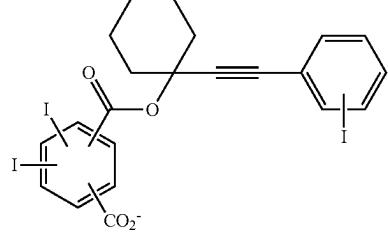
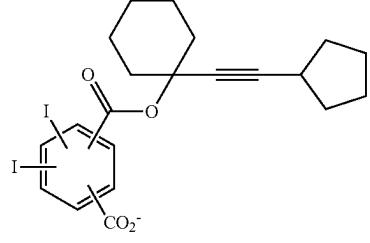
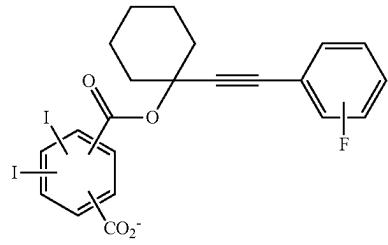
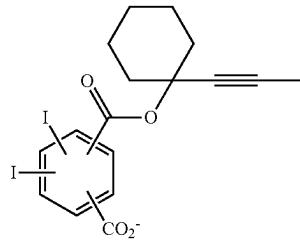
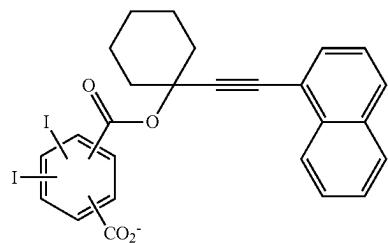
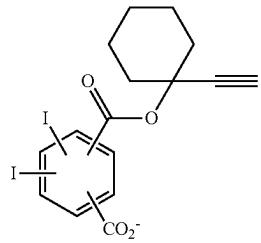
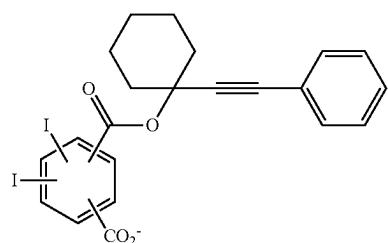
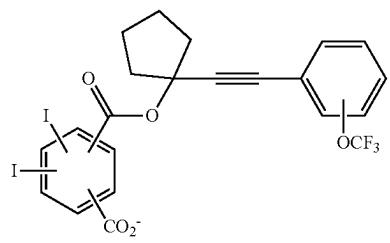
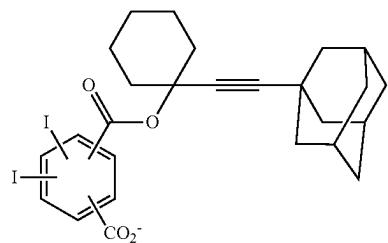
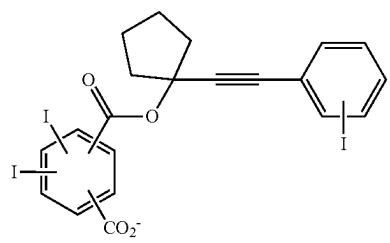
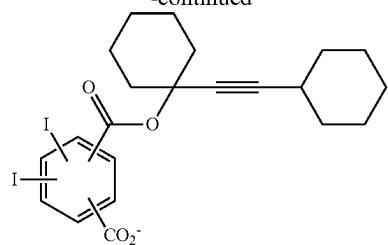




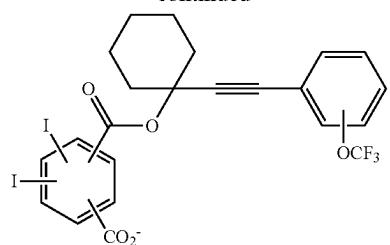
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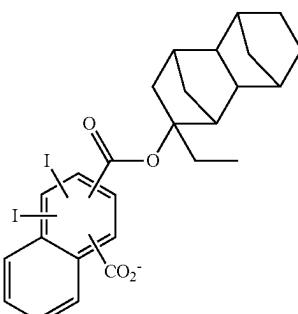
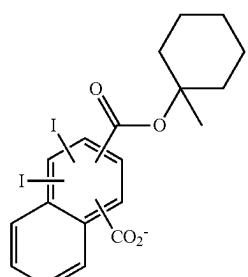
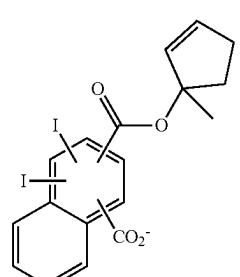
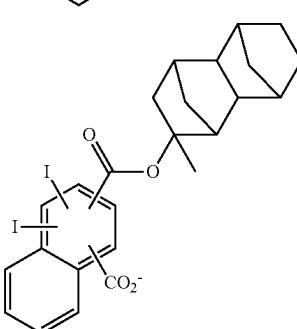
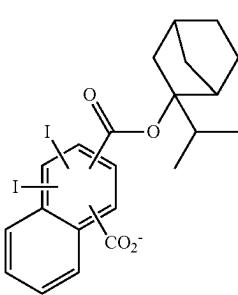
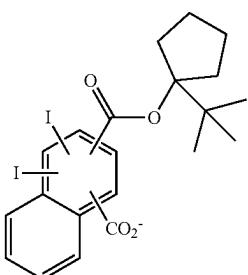
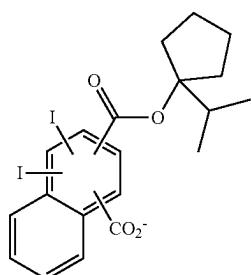
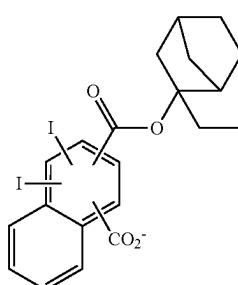
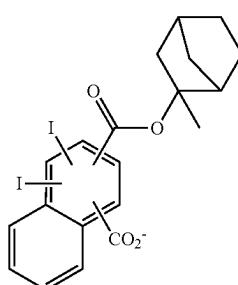
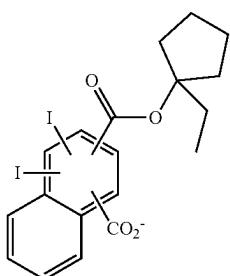
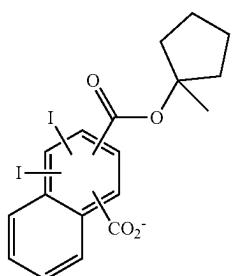
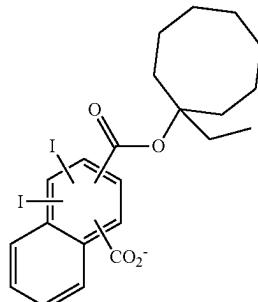
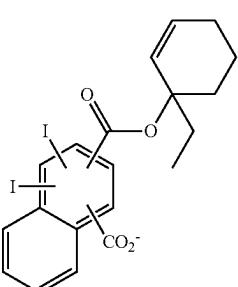
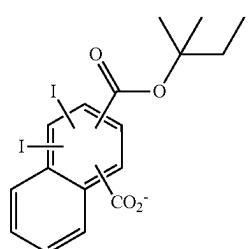
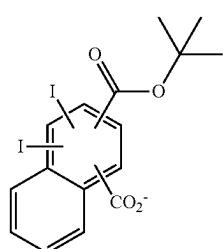
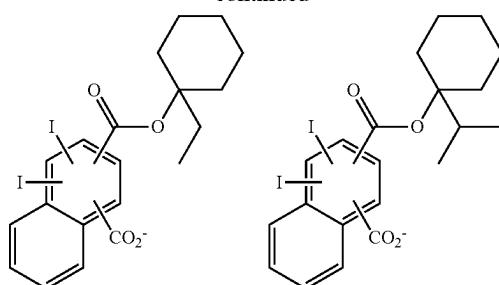
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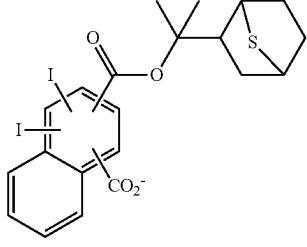
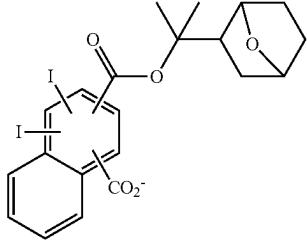
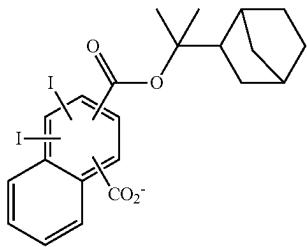
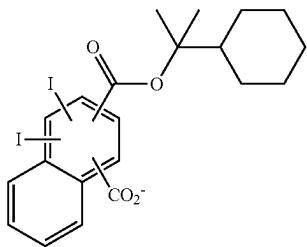
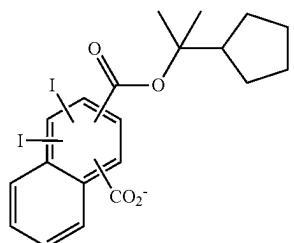
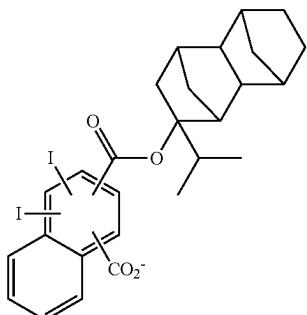
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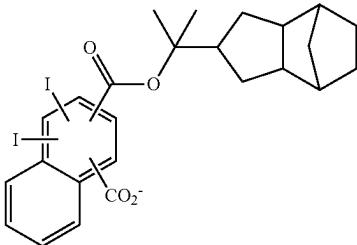
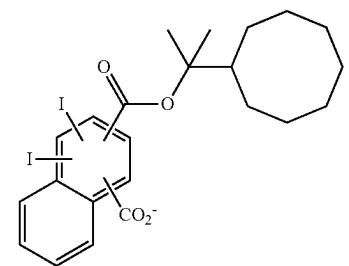
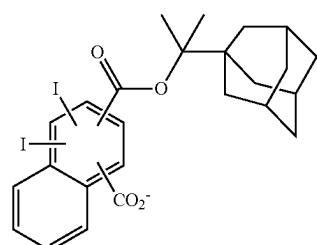
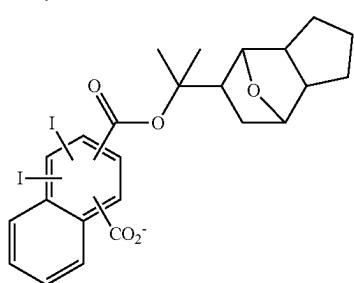
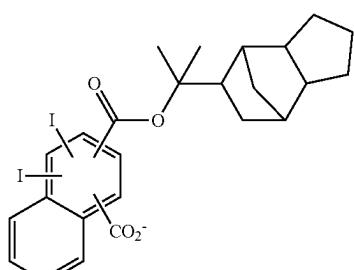
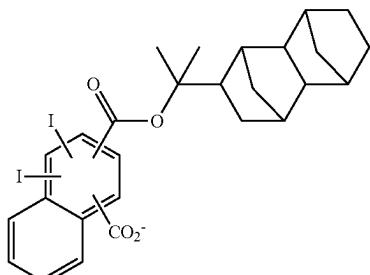
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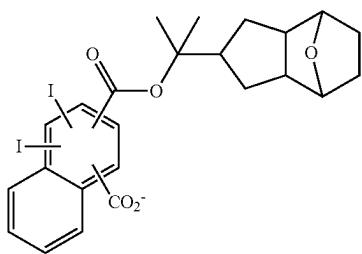
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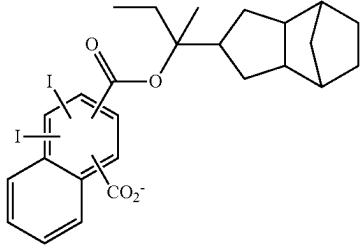
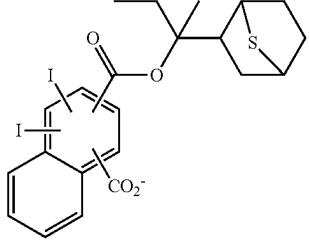
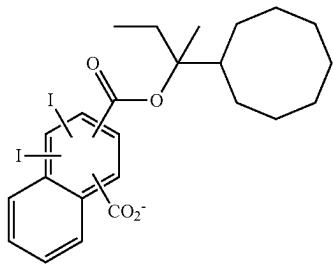
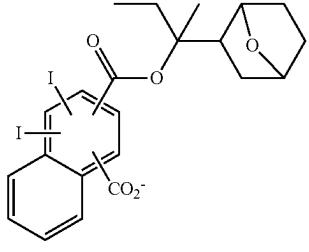
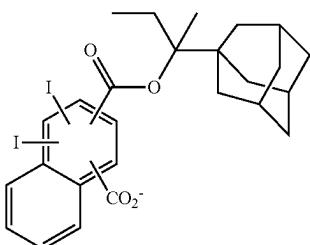
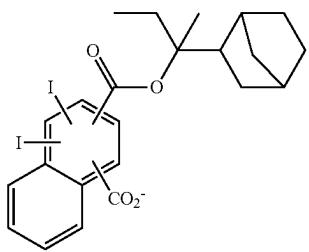
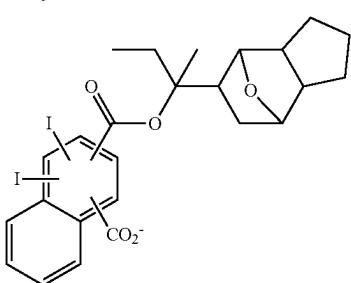
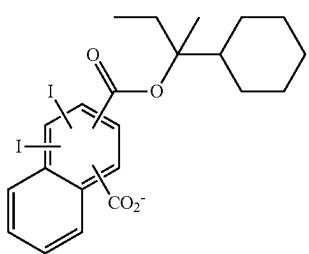
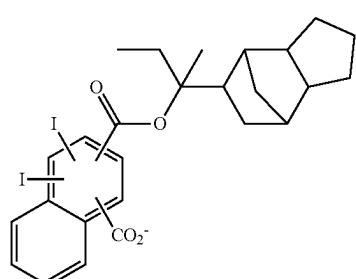
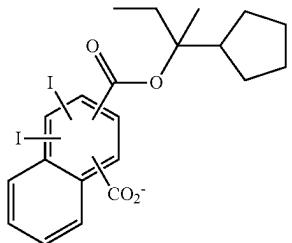
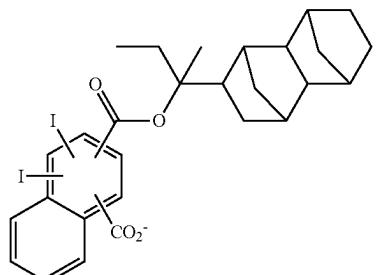
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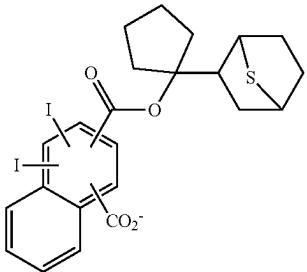
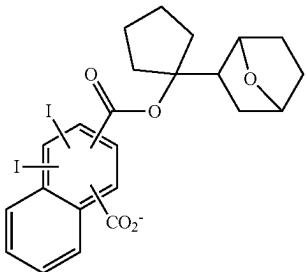
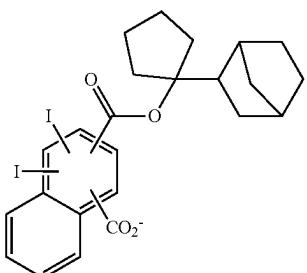
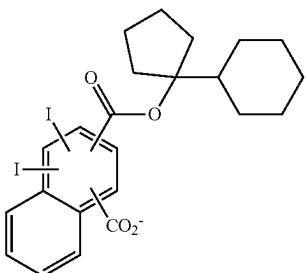
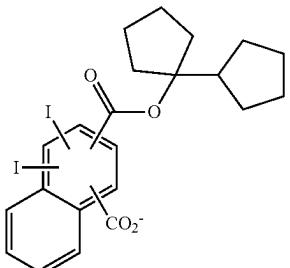
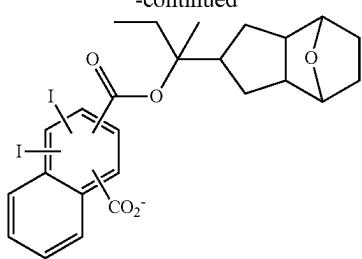
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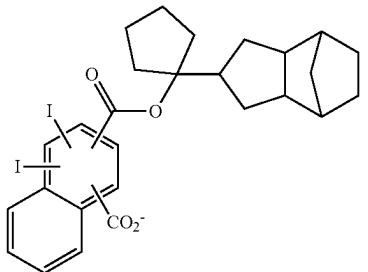
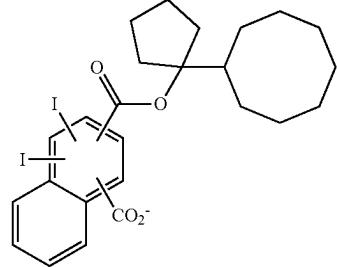
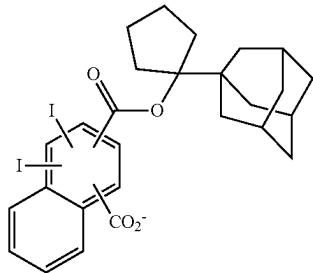
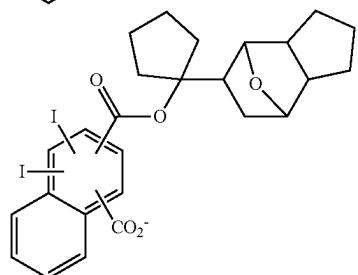
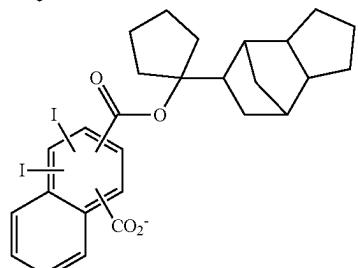
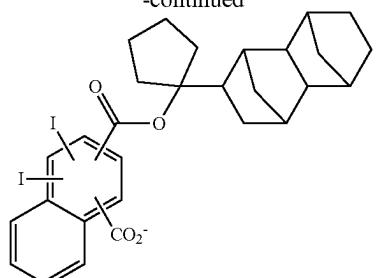
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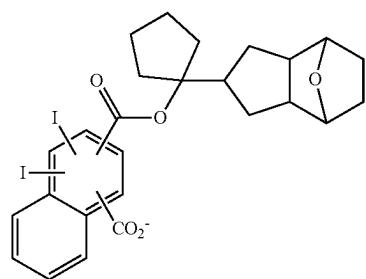
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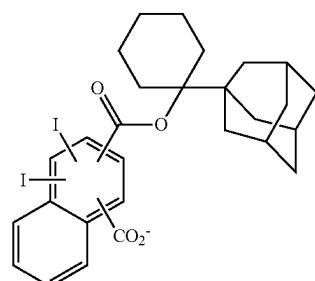
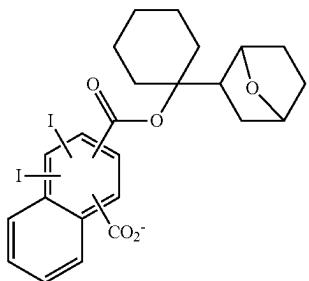
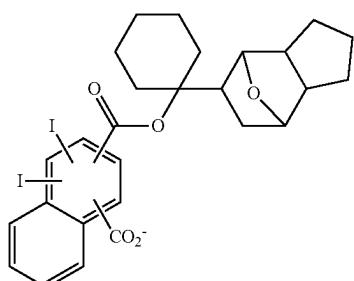
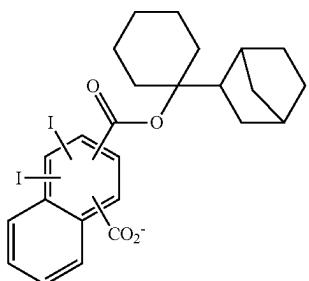
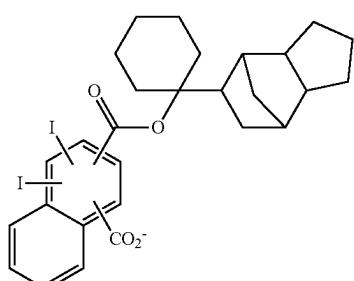
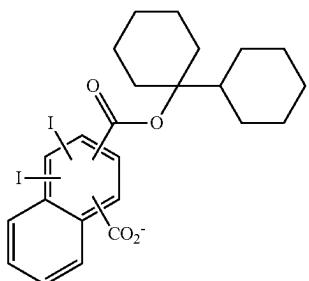
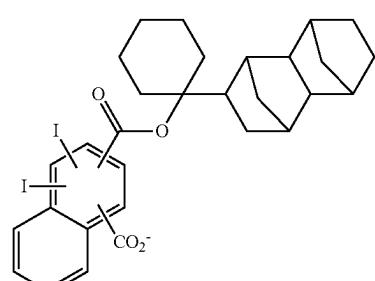
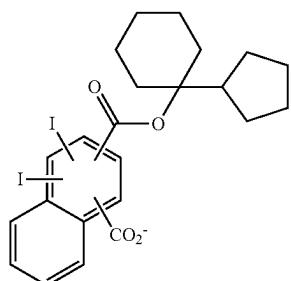
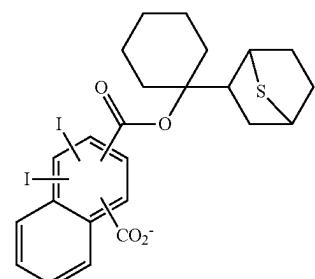
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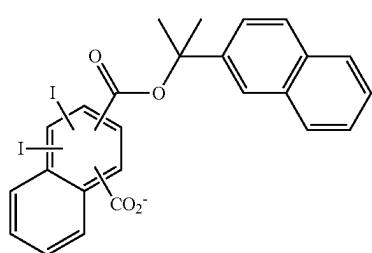
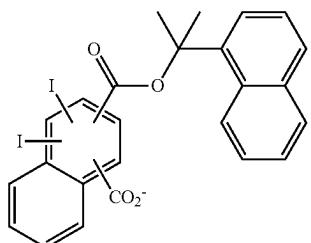
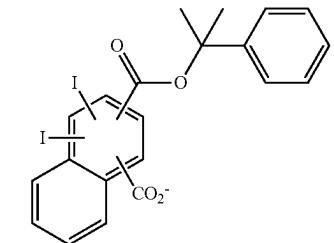
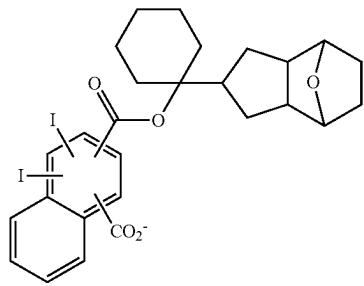
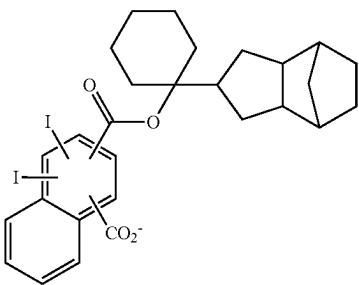
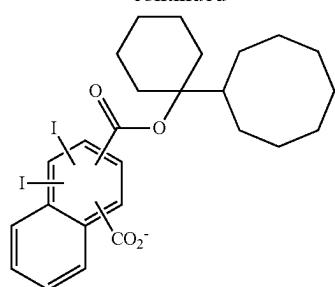
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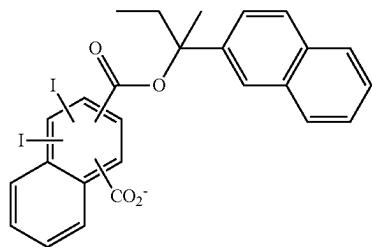
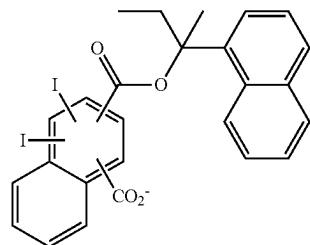
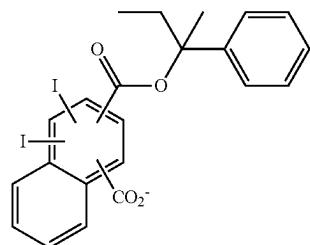
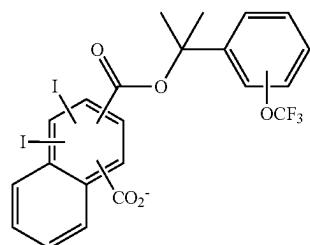
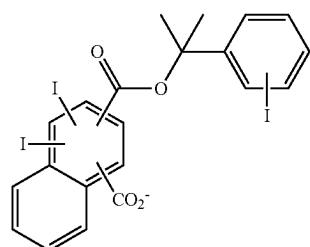
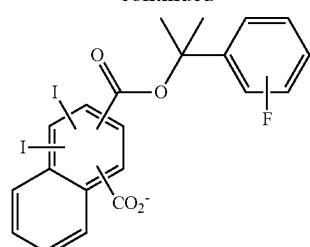
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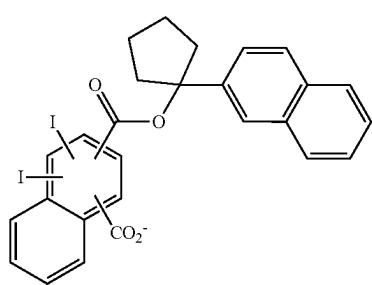
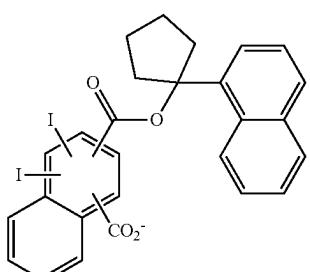
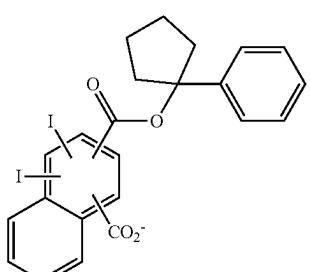
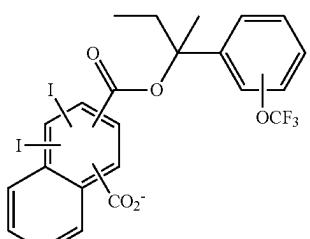
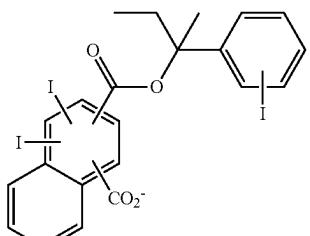
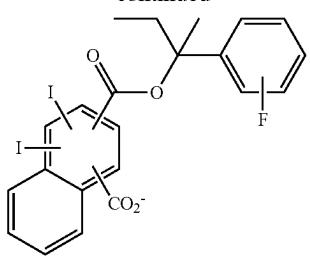
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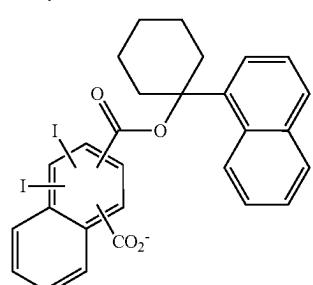
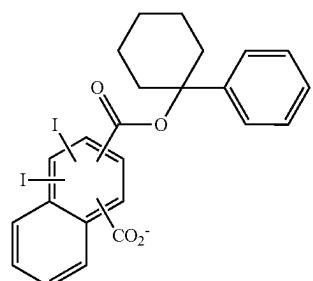
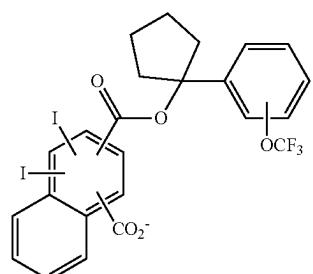
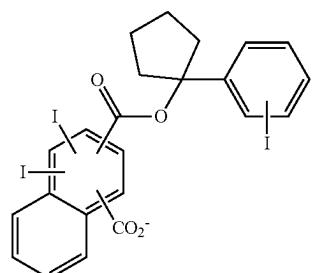
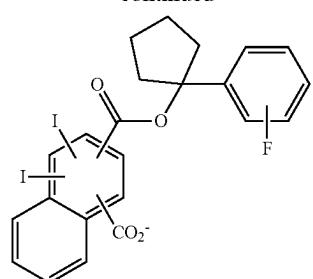
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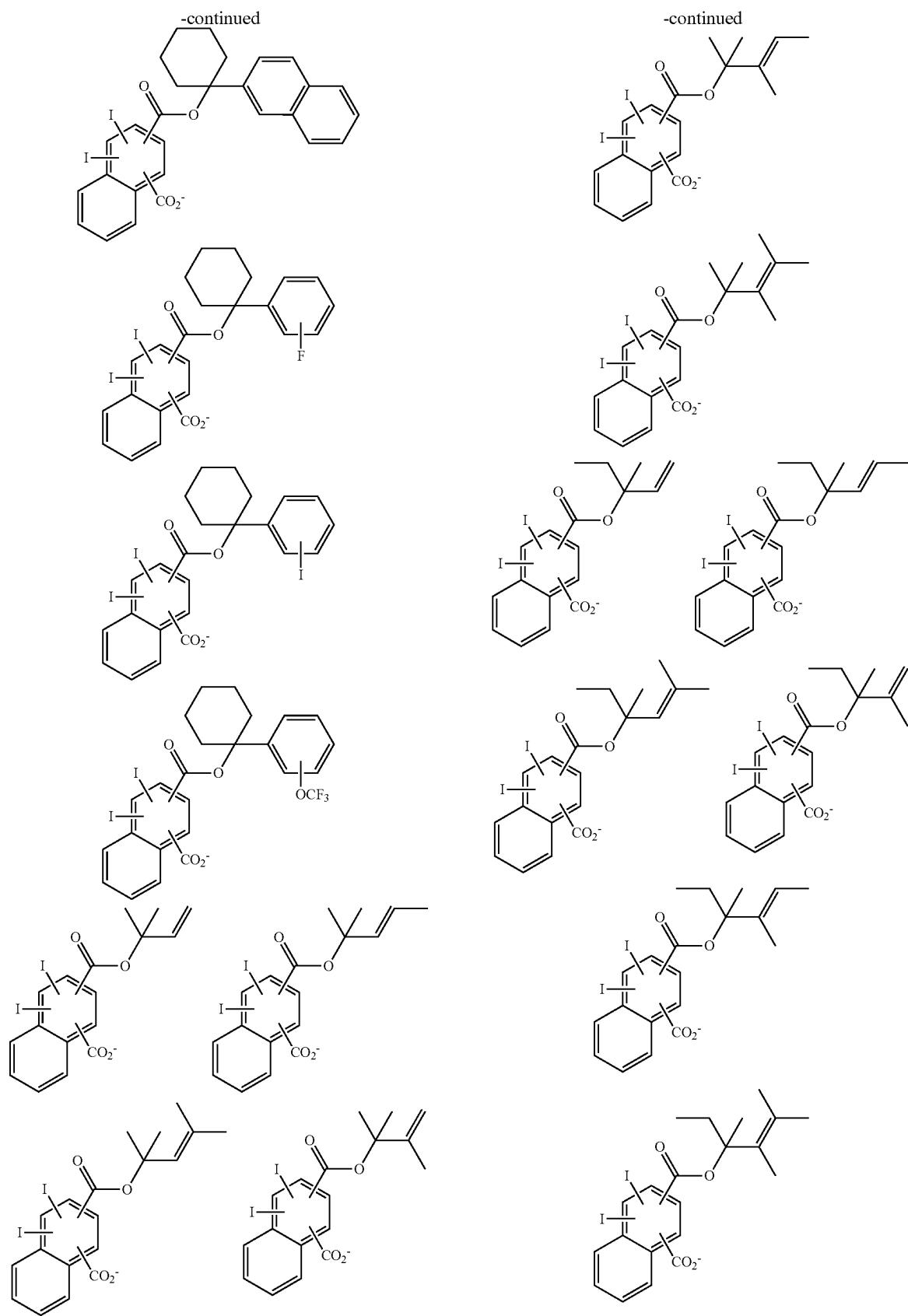


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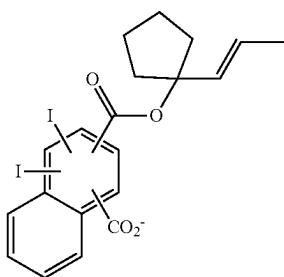
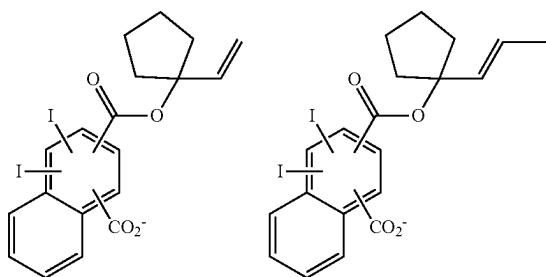


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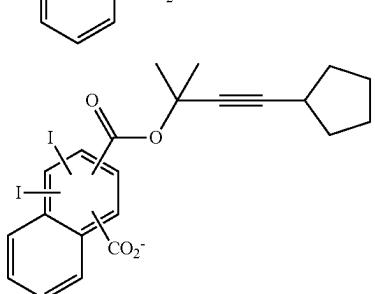
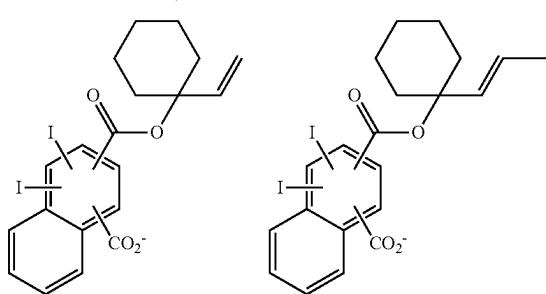
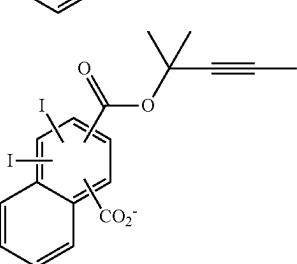
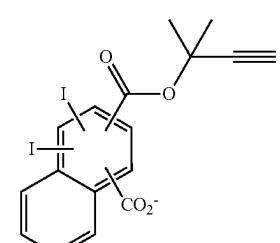
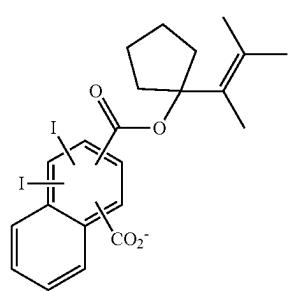
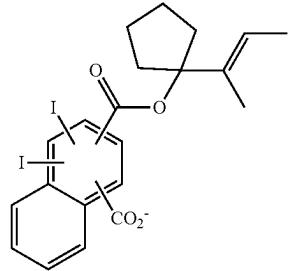
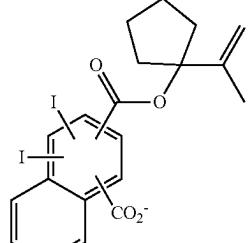
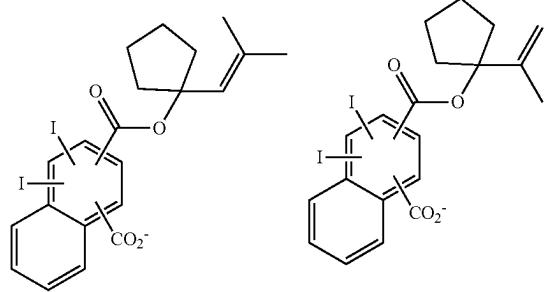
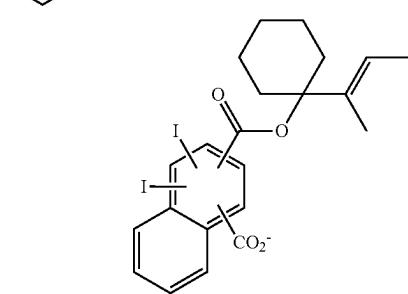
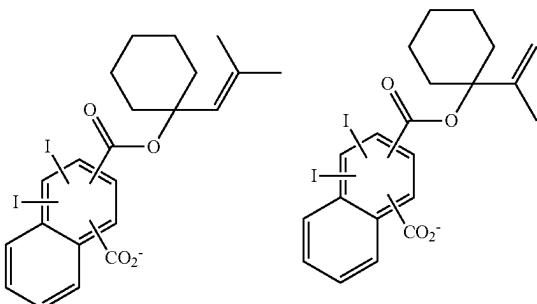




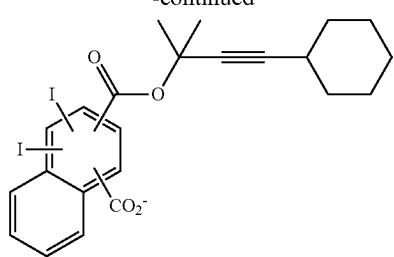
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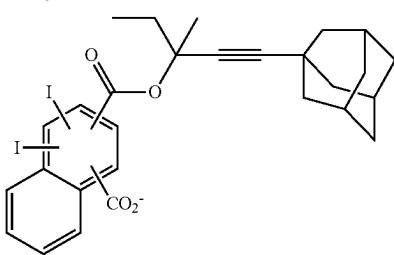
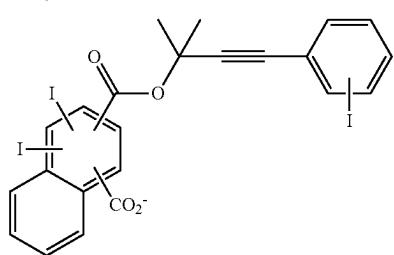
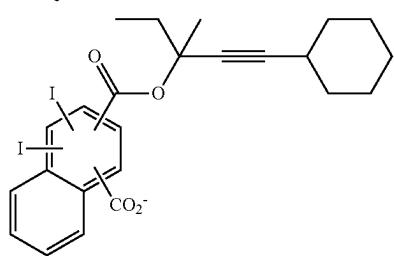
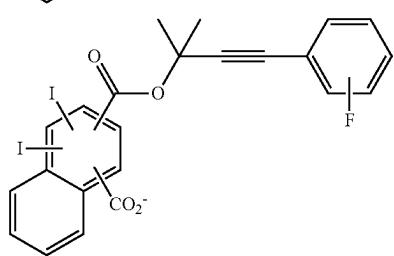
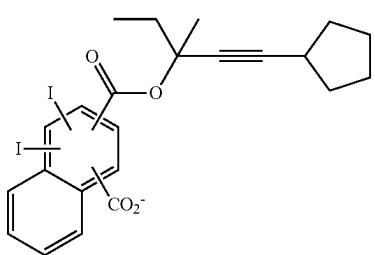
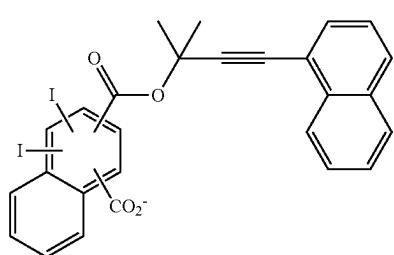
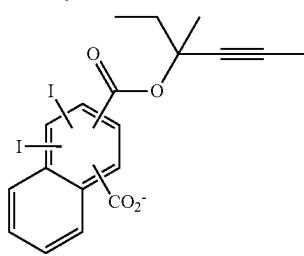
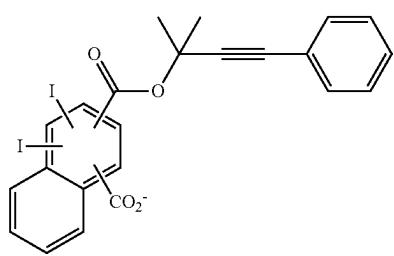
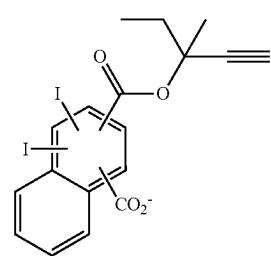
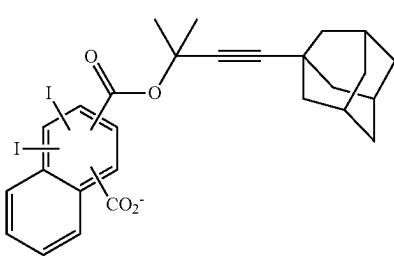
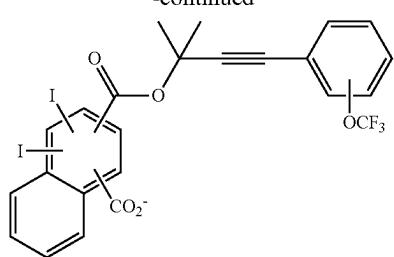
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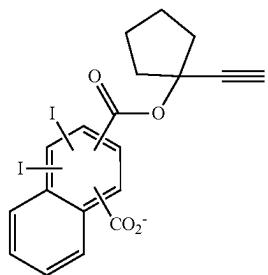
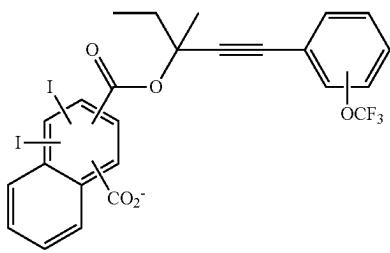
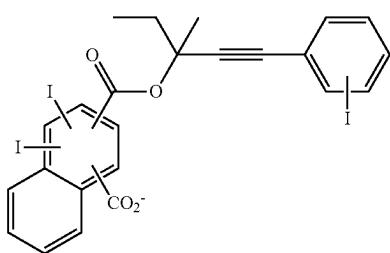
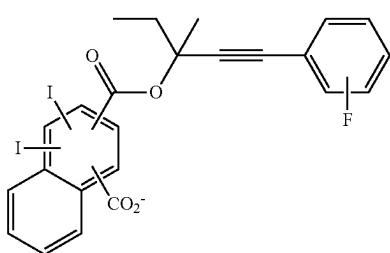
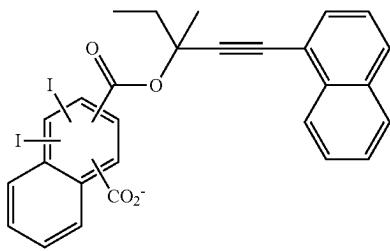
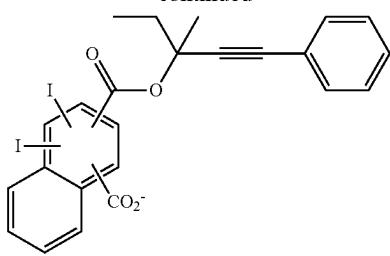
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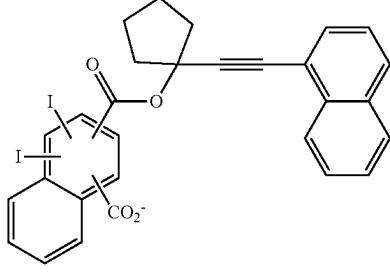
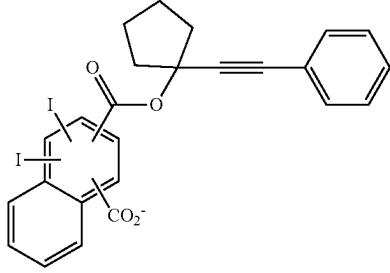
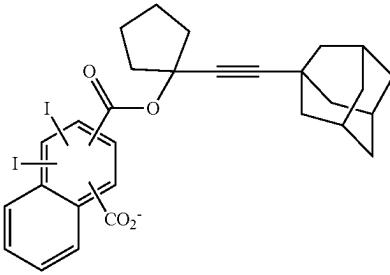
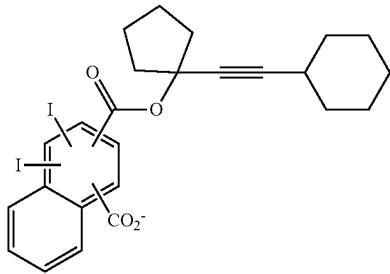
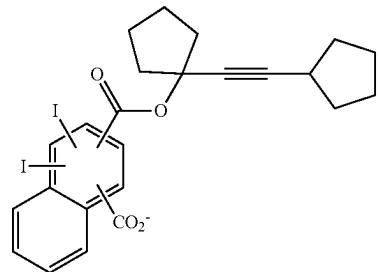
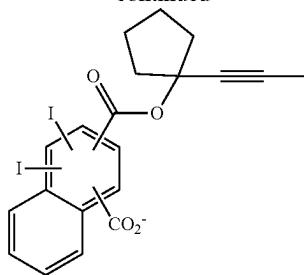
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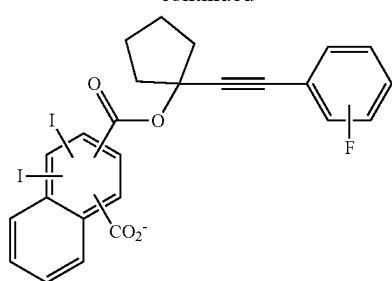
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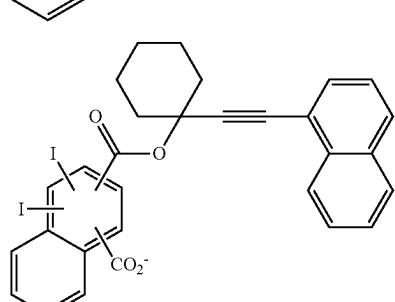
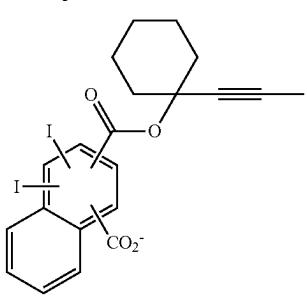
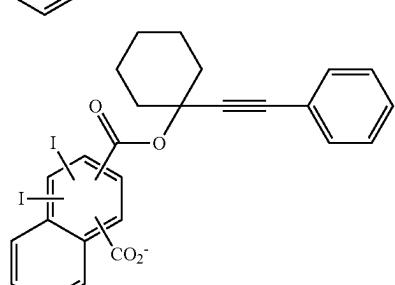
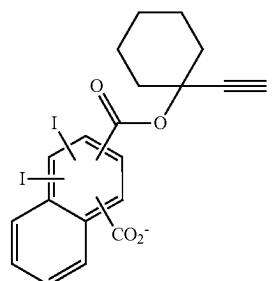
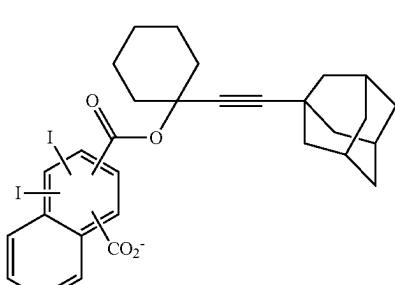
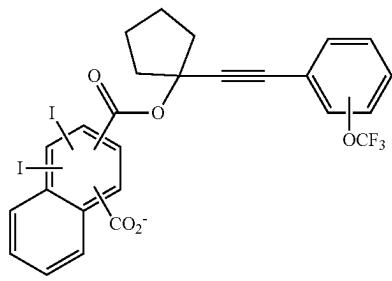
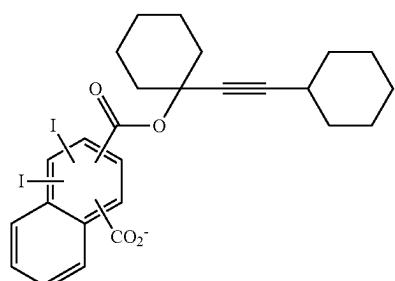
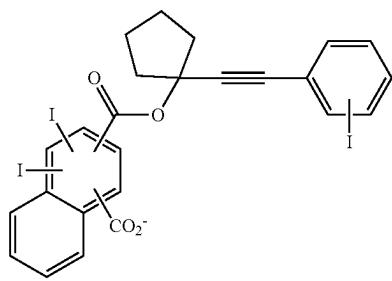
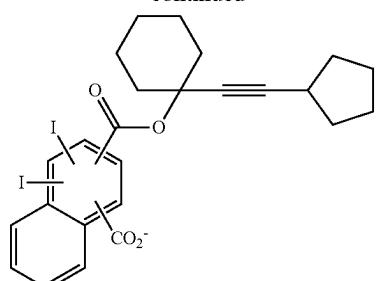
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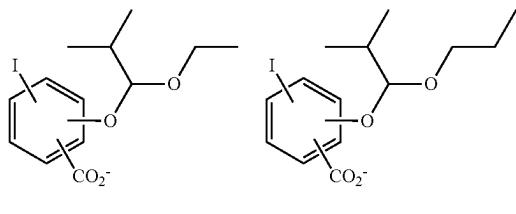
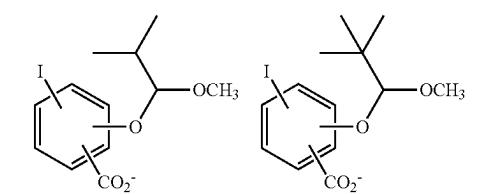
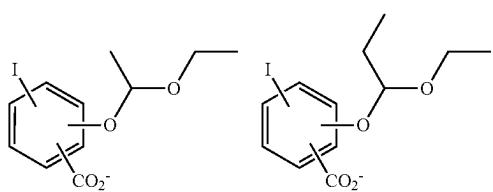
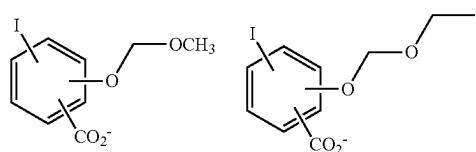
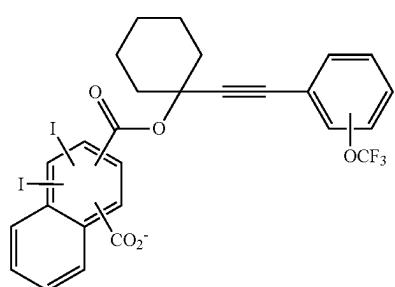
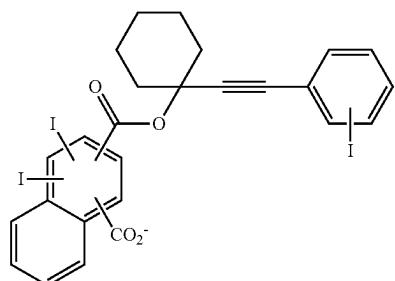
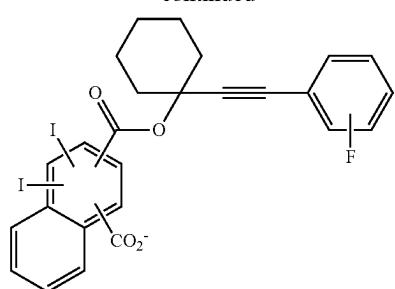
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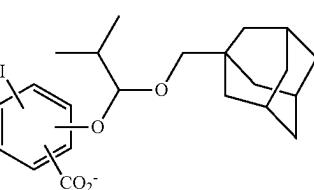
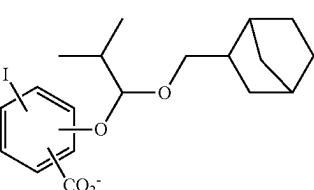
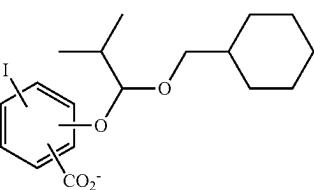
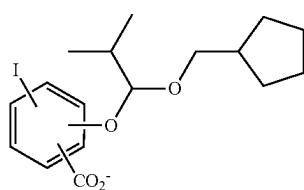
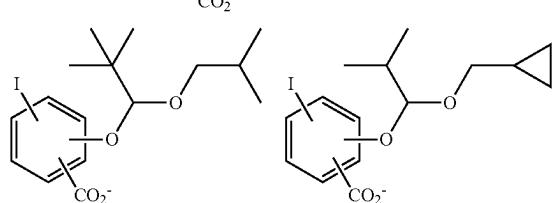
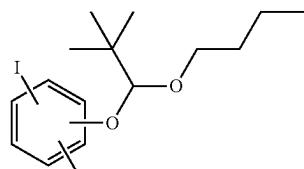
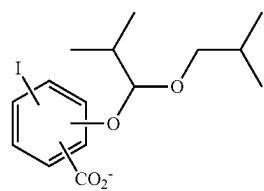
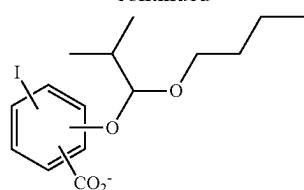
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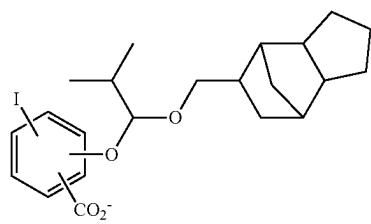
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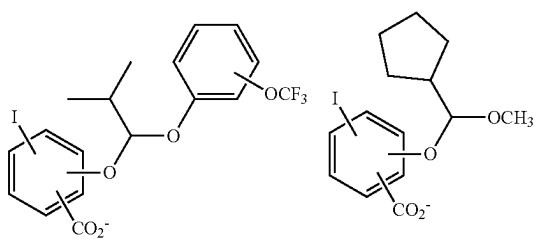
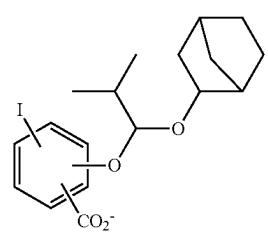
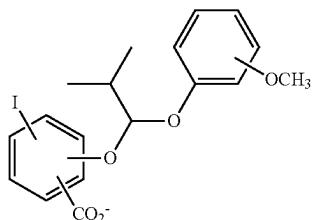
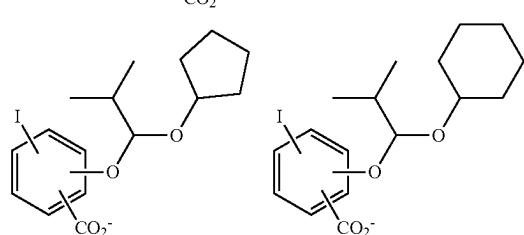
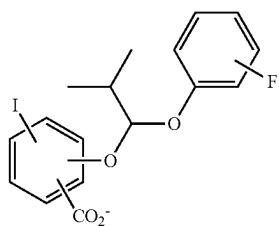
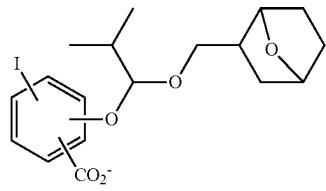
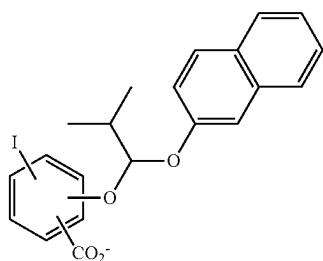
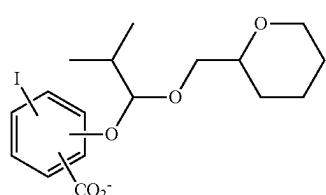
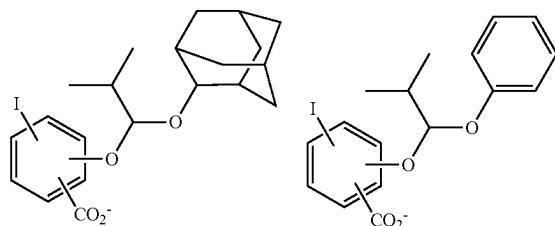
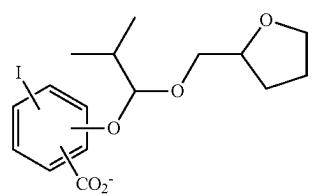
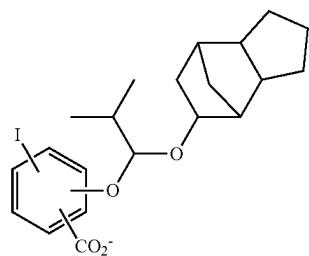
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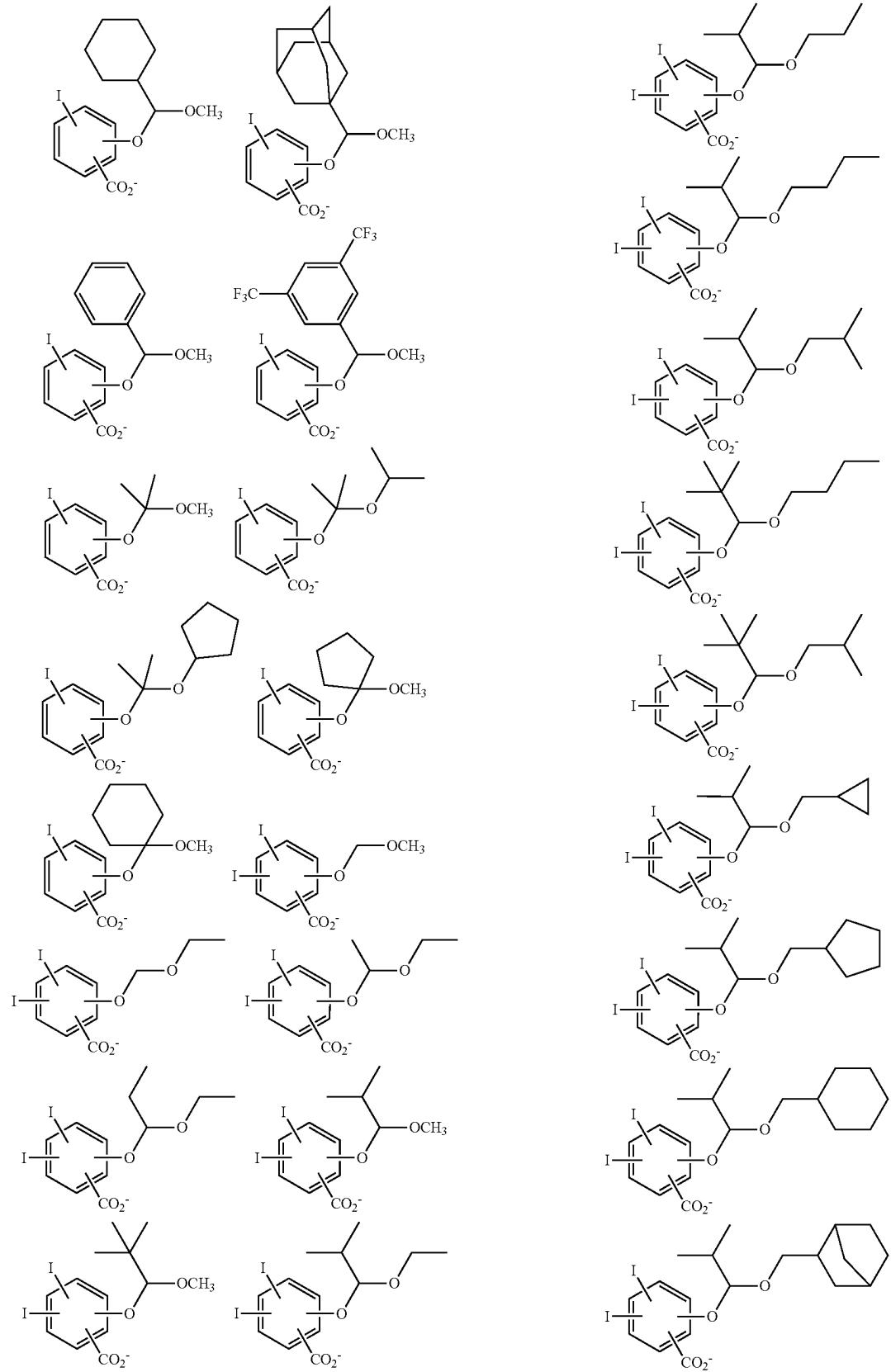
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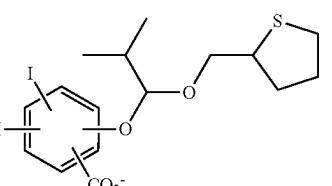
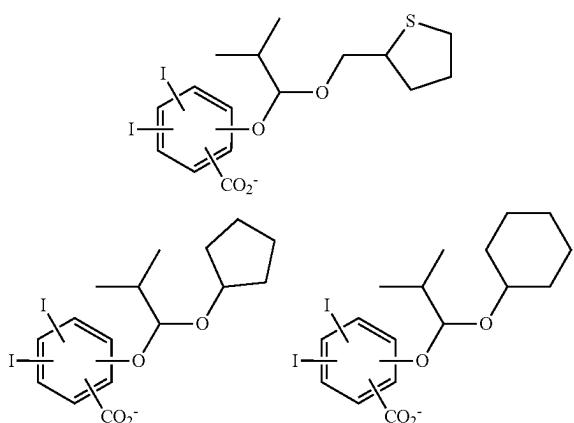
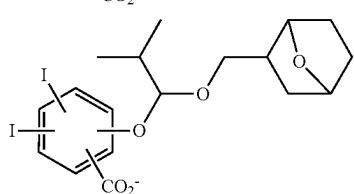
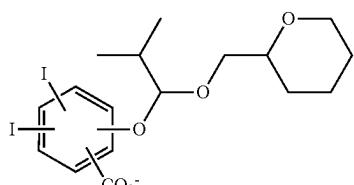
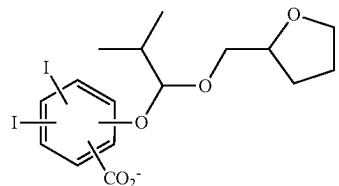
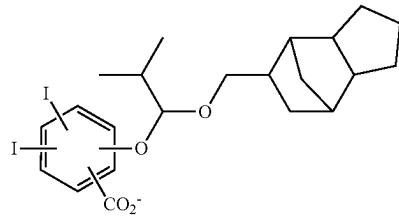
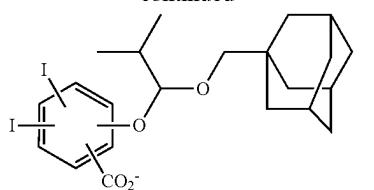
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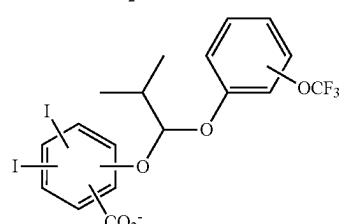
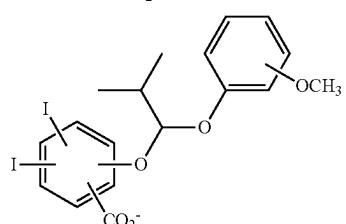
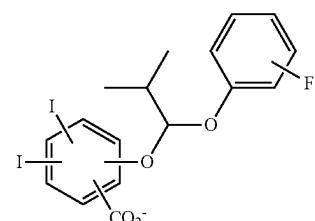
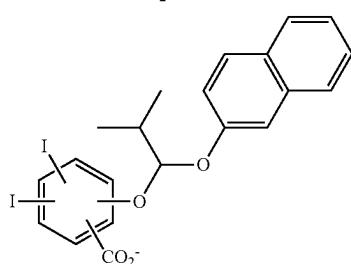
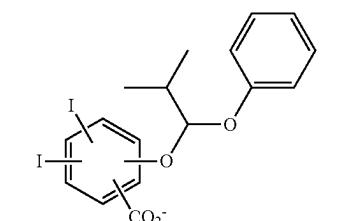
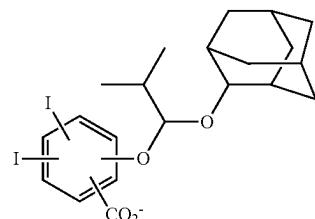
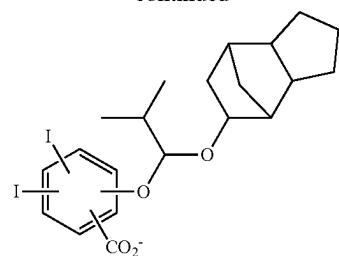
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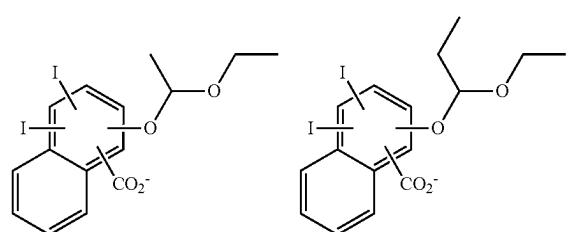
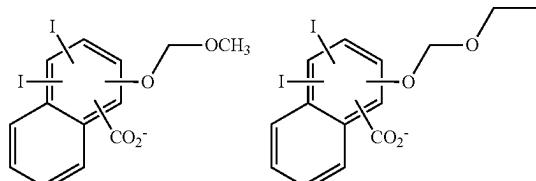
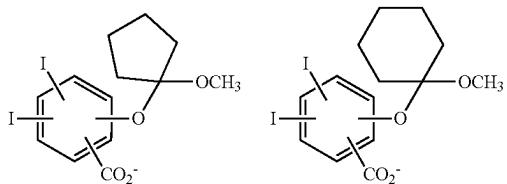
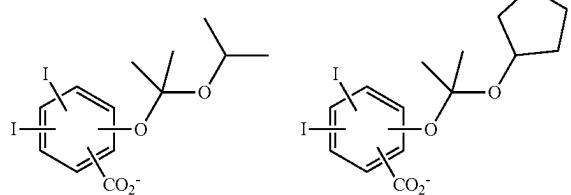
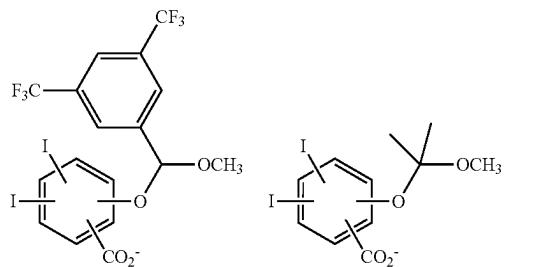
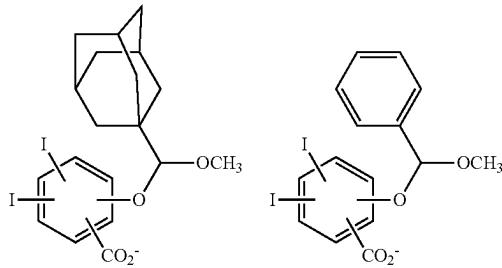
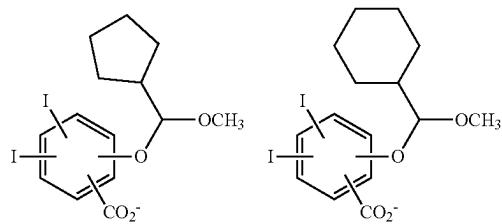
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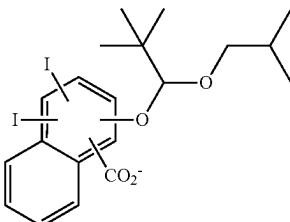
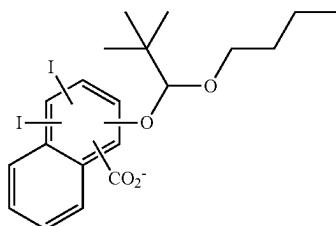
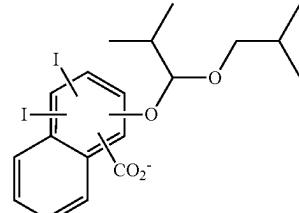
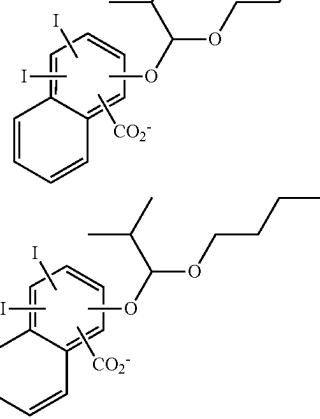
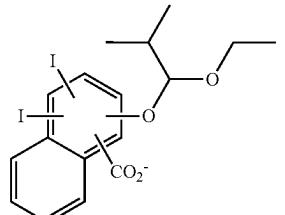
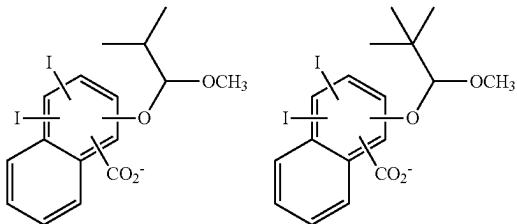
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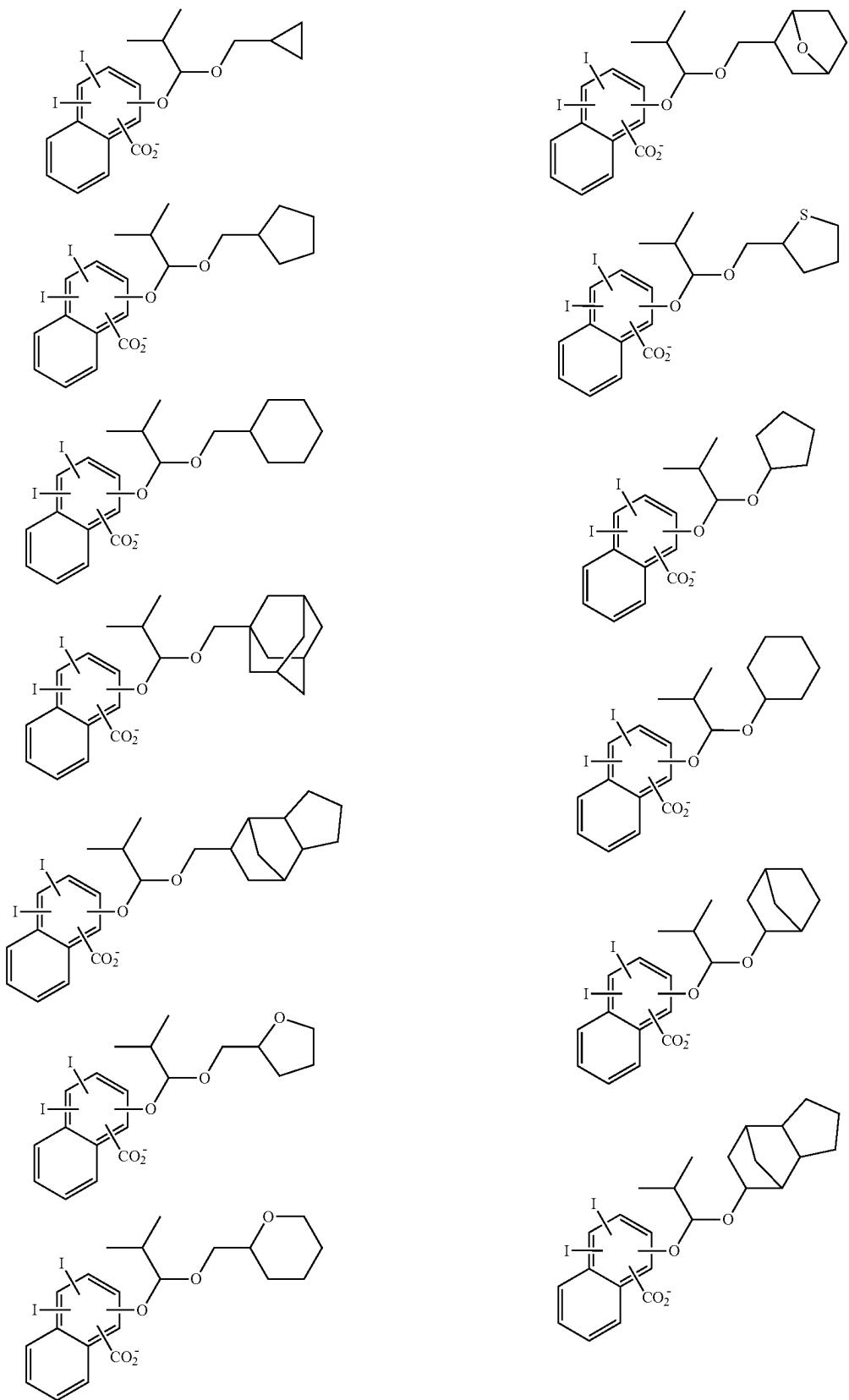
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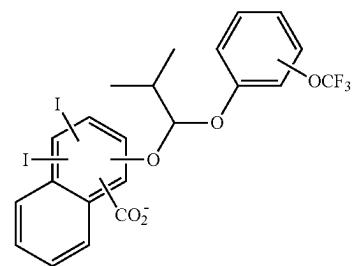
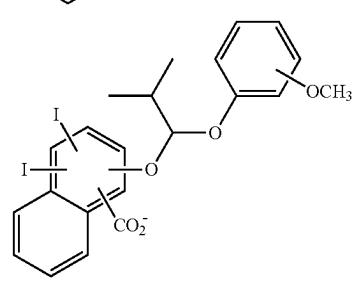
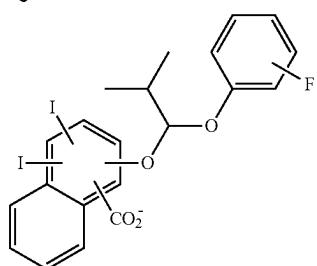
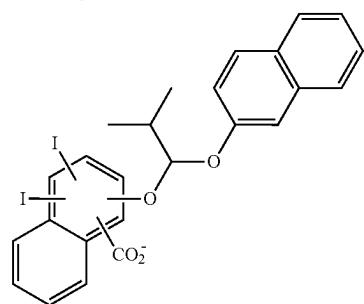
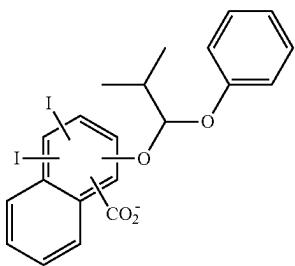
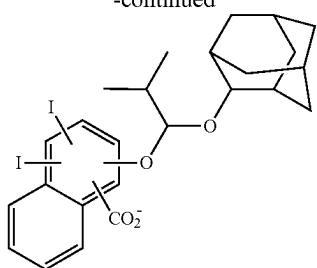
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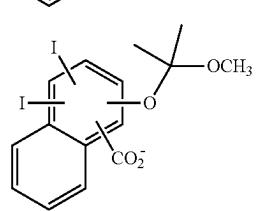
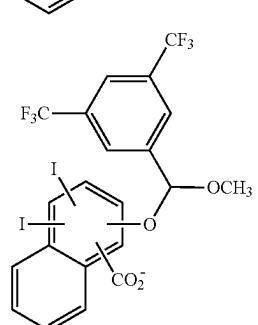
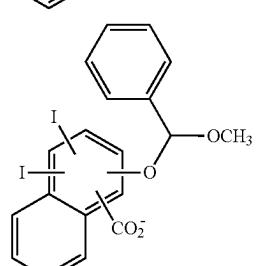
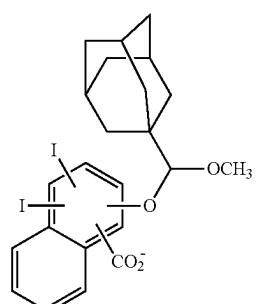
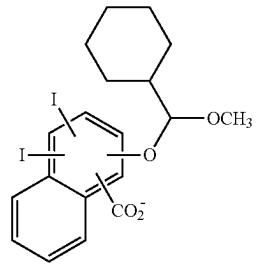
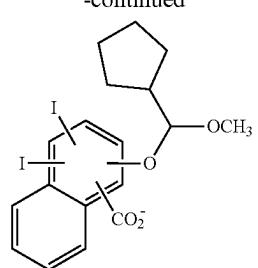
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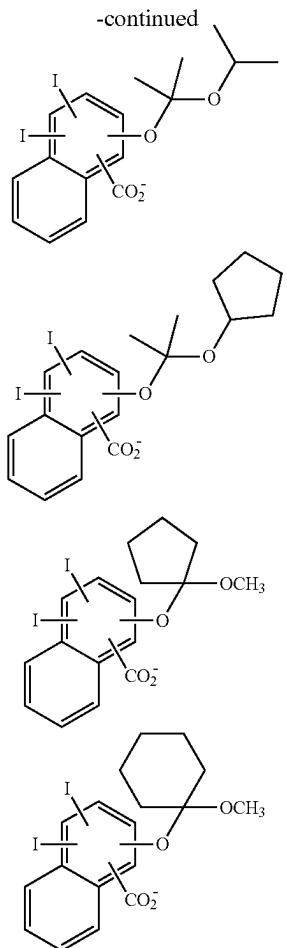


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[0159] Examples of the onium salt include arbitrary combinations of anions with cations, both as exemplified above.

[0160] The onium salt can be synthesized by a suitable method as described in JP-A 2020-091312 (U.S. Pat. No. 11,586,111), although the synthesis method is not limited thereto.

[0161] The onium salt of the invention is structurally characterized as consisting of a triaryl sulfonium cation containing iodine and fluorine and an aromatic carboxylic acid anion containing iodine. In the triaryl sulfonium cation containing iodine and fluorine, iodine which is outstandingly absorptive to EUV of wavelength 13.5 nm generates secondary electrons during EUV exposure. Also, the electron withdrawing effect of fluorine serves to lower the energy level of the lowest unoccupied molecular orbital (LUMO) of the frontier orbital theory so that the cation is more likely to accept the generated secondary electrons, whereby the decomposition of the cation is promoted and the acid is effectively generated. On the other hand, the aromatic carboxylic acid anion also generates secondary electrons because the anion also contains iodine, whereby the decomposition of the cation is promoted. The synergy of these effects results in a higher sensitivity. In addition, iodine has an appropriate dissolution inhibitory ability and is thus effective for restraining the pattern in the unexposed region from collapse in alkaline developer. In the embodiment wherein the anion has an acid labile group, deprotection

reaction of the acid labile group by the generated acid takes place to bring about a change of solubility, from which an enhancement of contrast and a higher sensitivity are expectable. In the exposed region of the positive resist film, as the affinity to alkaline developer is higher, the risk of development defects is lowered. The onium salt having an aromatic carboxylic acid anion has a relatively strong basicity whereby the strong acid generated from the PAG is effectively trapped. Due to the synergy of these effects, a chemically amplified resist composition comprising the inventive onium salt exhibits a high dissolution contrast and can form line patterns with reduced LWR and hole patterns with improved CDU, both the patterns having collapse resistance. The inventive onium salt is thus useful as one component of a chemically amplified resist composition, especially of positive tone.

[0162] The inventive onium salt is advantageously used as a quencher. As used herein, the term "quencher" refers to a compound capable of trapping the strong acid generated by a PAG in the resist composition to prevent the acid from diffusing to the unexposed region and to assist in forming the desired pattern. As used herein, the "PAG" refers to a compound capable of generating a strong acid upon exposure to high-energy radiation, and the term "strong acid" refers to a compound having a sufficient acidity to induce deprotection reaction of an acid labile group. Since the aromatic carboxylic acid does not have an enough acidity to induce deprotection reaction of an acid labile group which is tertiary ester or tertiary ether, it is effective to separately add a PAG capable of generating a strong acid, i.e., α -fluorinated sulfonic acid, imide acid or methide acid, for the purpose of inducing deprotection reaction of an acid labile group, as will be described later. It is noted that the PAG capable of generating an α -fluorinated sulfonic acid, imide acid or methide acid may be of addition type or of polymer-bound type wherein the PAG is bound to a base polymer.

[0163] In a system where the inventive onium salt capable of generating an aromatic carboxylic acid and a PAG capable of generating a ultra-strong acid or perfluoroalkylsulfonic acid are co-present, the aromatic carboxylic acid and the perfluoroalkylsulfonic acid generate upon light exposure. Since the PAG is not decomposed in its entirety, some PAG remains undecomposed nearby. If the onium salt capable of generating an aromatic carboxylic acid and perfluoroalkylsulfonic acid are co-present at this point of time, first an ion exchange occurs between the perfluoroalkylsulfonic acid and the onium salt capable of generating an aromatic carboxylic acid whereby an onium salt of perfluoroalkylsulfonic acid is generated and the aromatic carboxylic acid is released. This is because the perfluoroalkylsulfonic acid salt having a high acid strength is more stable. On the other hand, where the perfluoroalkylsulfonic acid onium salt and the aromatic carboxylic acid are co-present, no ion exchange occurs. Similar ion exchange takes place not only with the perfluoroalkylsulfonic acid, but also with an arene sulfonic acid, alkyl sulfonic acid, imide acid or methide acid having a higher acid strength than the aromatic carboxylic acid generated by the inventive onium salt.

[Chemically Amplified Resist Composition]

(A) Quencher

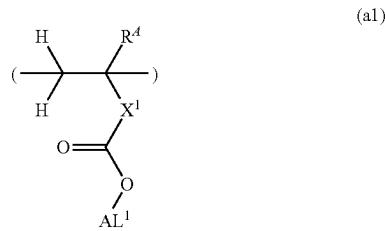
[0164] Another embodiment of the invention is a chemically amplified resist composition essentially comprising

(A) a quencher in the form of the onium salt consisting of a cation having the formula (1A) and an anion having the formula (1B).

[0165] In the chemically amplified resist composition, the amount of quencher (A) is preferably 0.1 to 40 parts by weight, more preferably 0.5 to 30 parts by weight per 80 parts by weight of a base polymer to be described just below. As long as the amount of quencher (A) is in the range, good sensitivity and resolution are achievable and the risk of foreign particles being formed after development or during stripping of resist film is avoided. The quencher may be used alone or in admixture.

(B) Base Polymer

[0166] The chemically amplified resist composition may comprise a base polymer as component (B). The base polymer (B) contains repeat units having the formula (a1), which are also referred to as repeat units (a1).

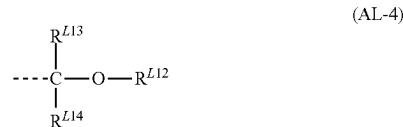
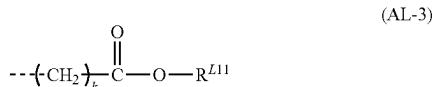


[0167] In formula (a1), R⁴ is hydrogen, fluorine, methyl or trifluoromethyl.

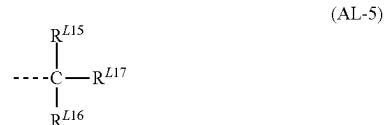
[0168] In formula (a1), X¹ is a single bond, phenylene group, naphthylene group, *—C(=O)—O—X¹¹— or *—C(=O)—NH—X¹¹—. The phenylene or naphthylene group may be substituted with an optionally fluorinated C₁-C₁₀ alkoxy moiety or halogen. X¹¹ is a C₁-C₁₀ saturated hydrocarbylene group, phenylene or naphthylene group, and the saturated hydrocarbylene group may contain a hydroxy moiety, ether bond, ester bond or lactone ring. The asterisk (*) designates a point of attachment to the carbon atom in the backbone.

[0169] In formula (a1), AL¹ is an acid labile group. Examples of the acid labile group include those described in U.S. Pat. No. 8,574,817 (JP-A 2013-080033) and U.S. Pat. No. 8,846,303 (JP-A 2013-083821).

[0170] Typical of the acid labile group are groups of the following formulae (AL-3) to (AL-5).



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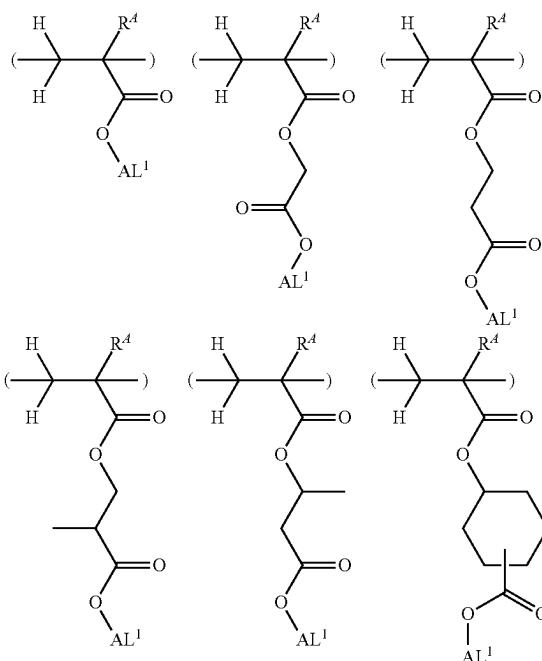
[0171] In formulae (AL-3) and (AL-4), R^{L11} and R^{L12} are each independently a C₁-C₄₀ hydrocarbyl group which may contain a heteroatom such as oxygen, sulfur, nitrogen or fluorine. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Inter alia, C₁-C₂₀ hydrocarbyl groups are preferred.

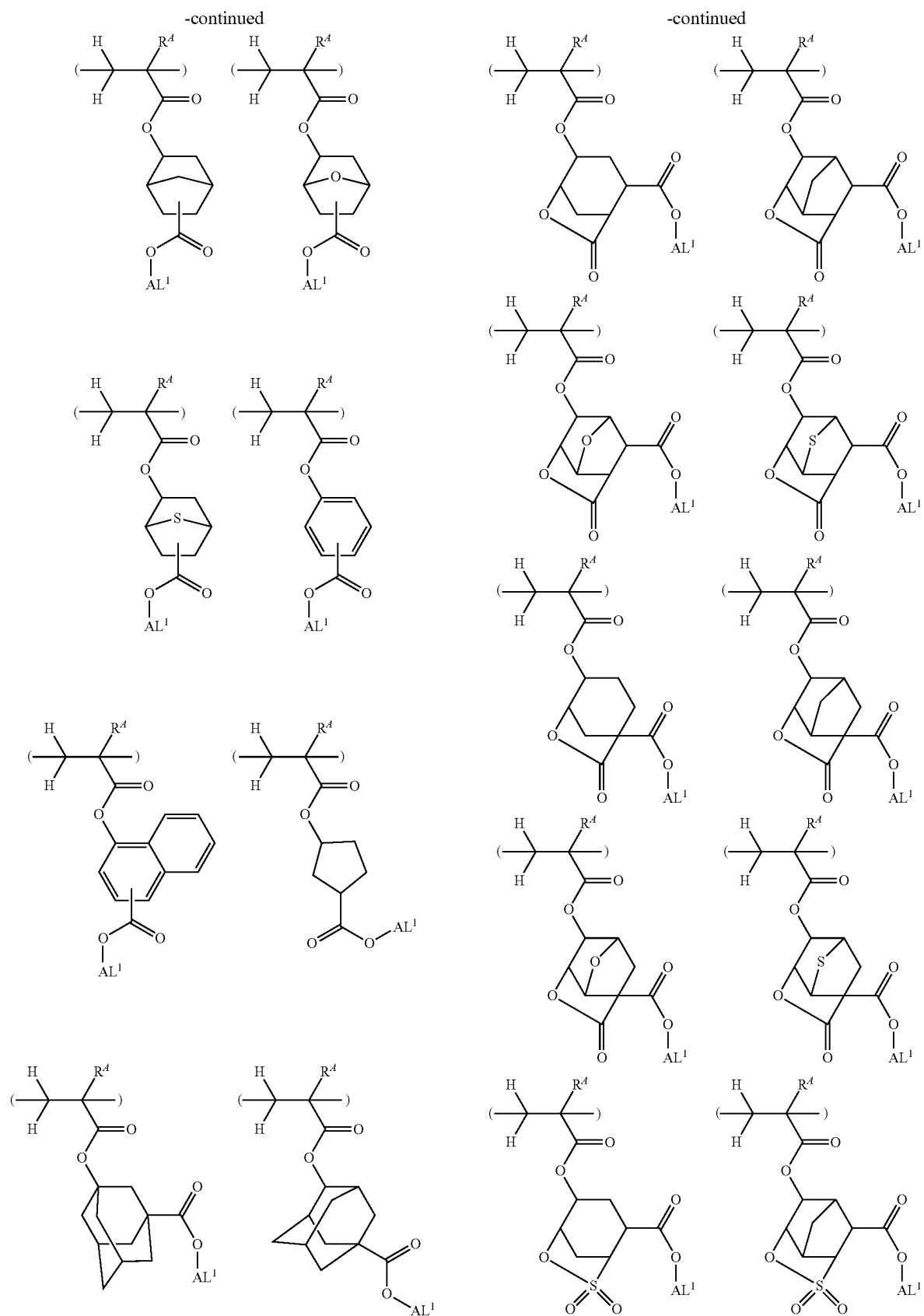
[0172] In formula (AL-3), k is an integer of 0 to 10, preferably 1 to 5.

[0173] In formula (AL-4), R^{L13} and R^{L14} are each independently hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom such as oxygen, sulfur, nitrogen or fluorine. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Any two of R^{L2}, R^{L13} and R^{L14} may bond together to form a C₃-C₂₀ ring with the carbon atom or carbon and oxygen atoms to which they are attached. The ring preferably contains 4 to 16 carbon atoms and is typically alicyclic.

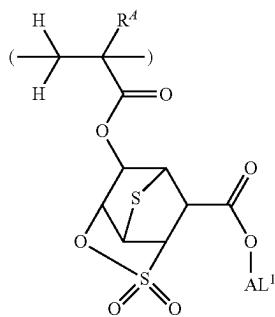
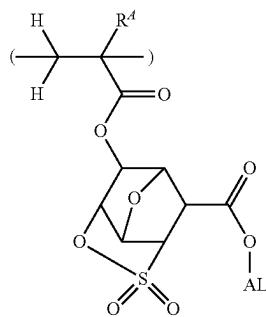
[0174] In formula (AL-5), R^{L1}, R^{L16} and R^{L17} are each independently a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom such as oxygen, sulfur, nitrogen or fluorine. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Any two of R^{L1}, R^{L16} and R^{L17} may bond together to form a C₃-C₂₀ ring with the carbon atom to which they are attached. The ring preferably contains 4 to 16 carbon atoms and is typically alicyclic.

[0175] Examples of repeat unit (a1) are shown below, but not limited thereto. Herein R⁴ and AL¹ are as defined above.

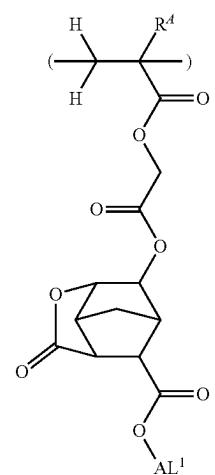
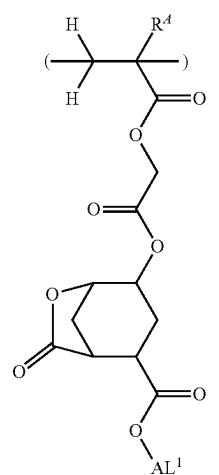
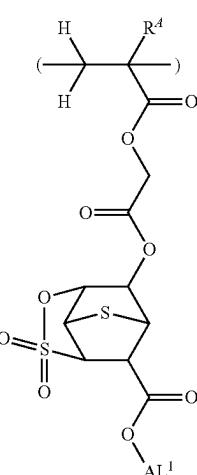
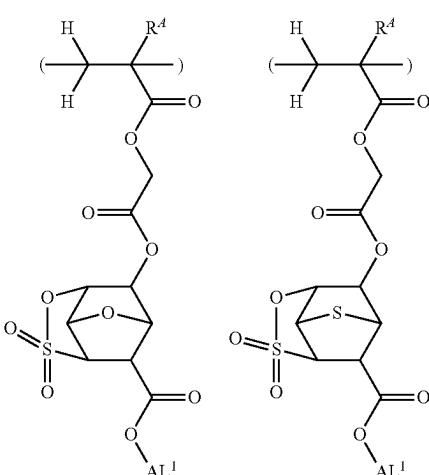
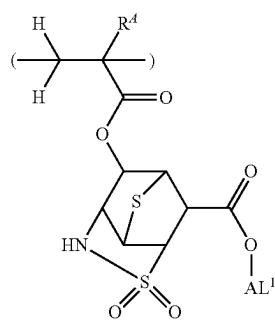
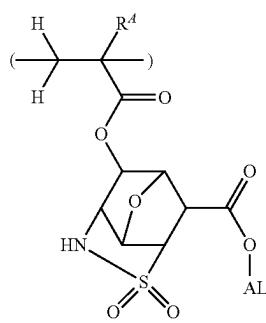
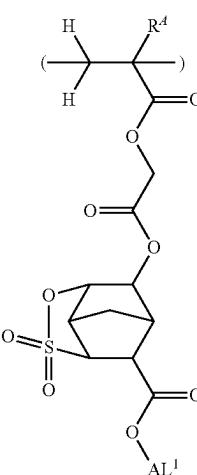
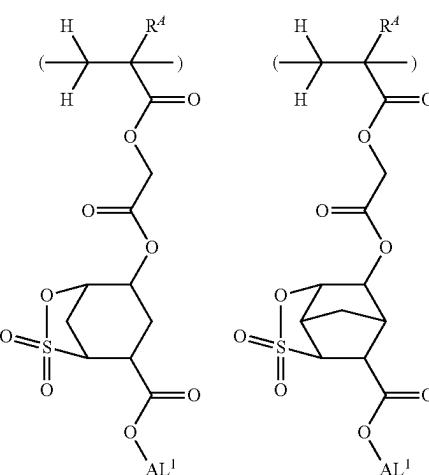
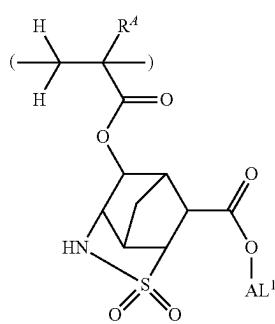
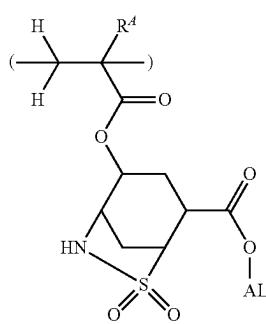
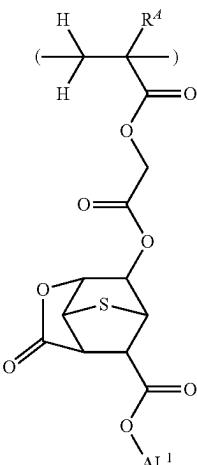
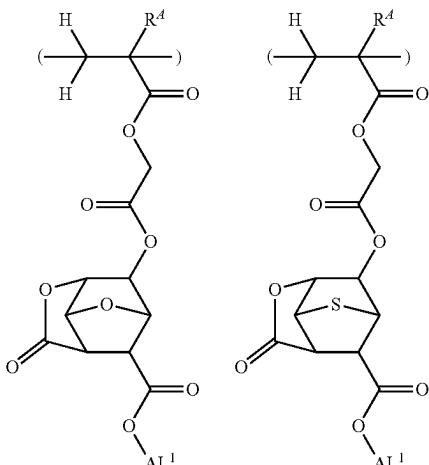




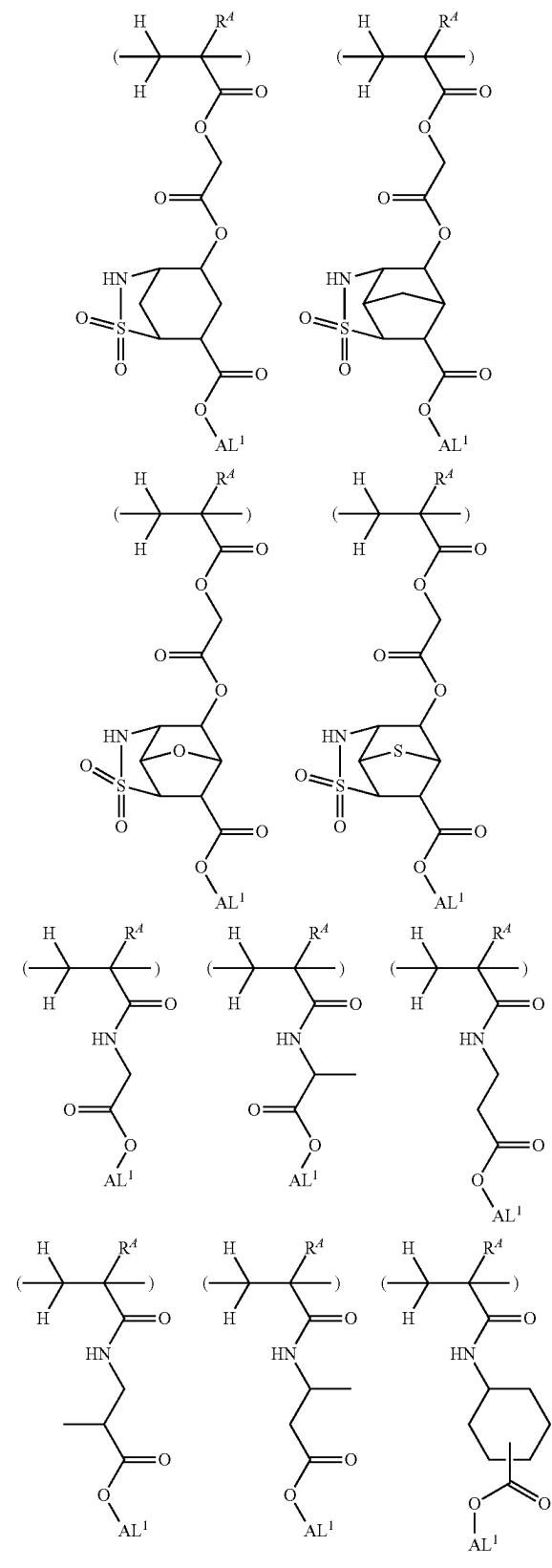
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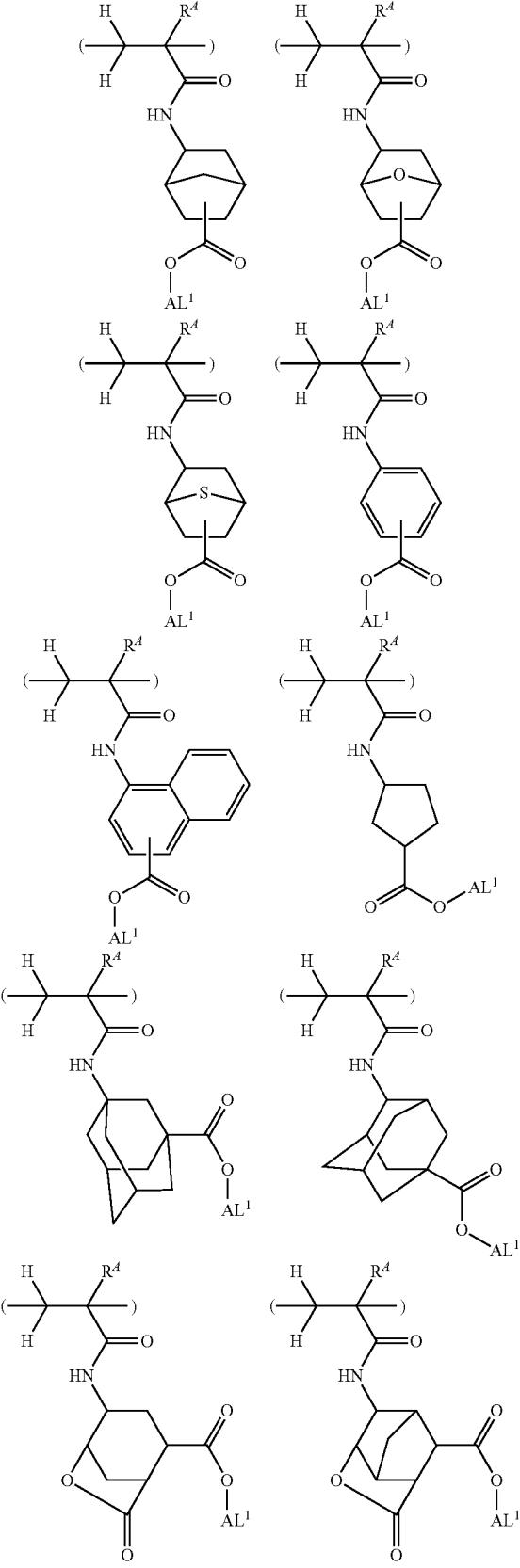
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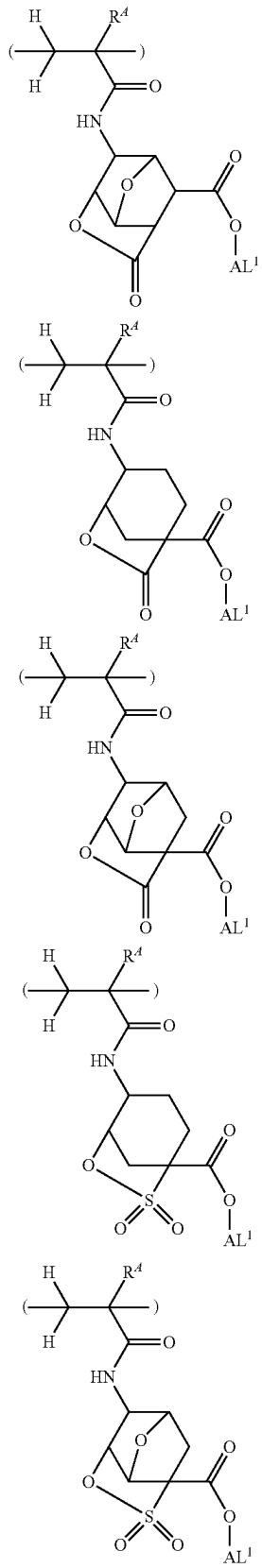
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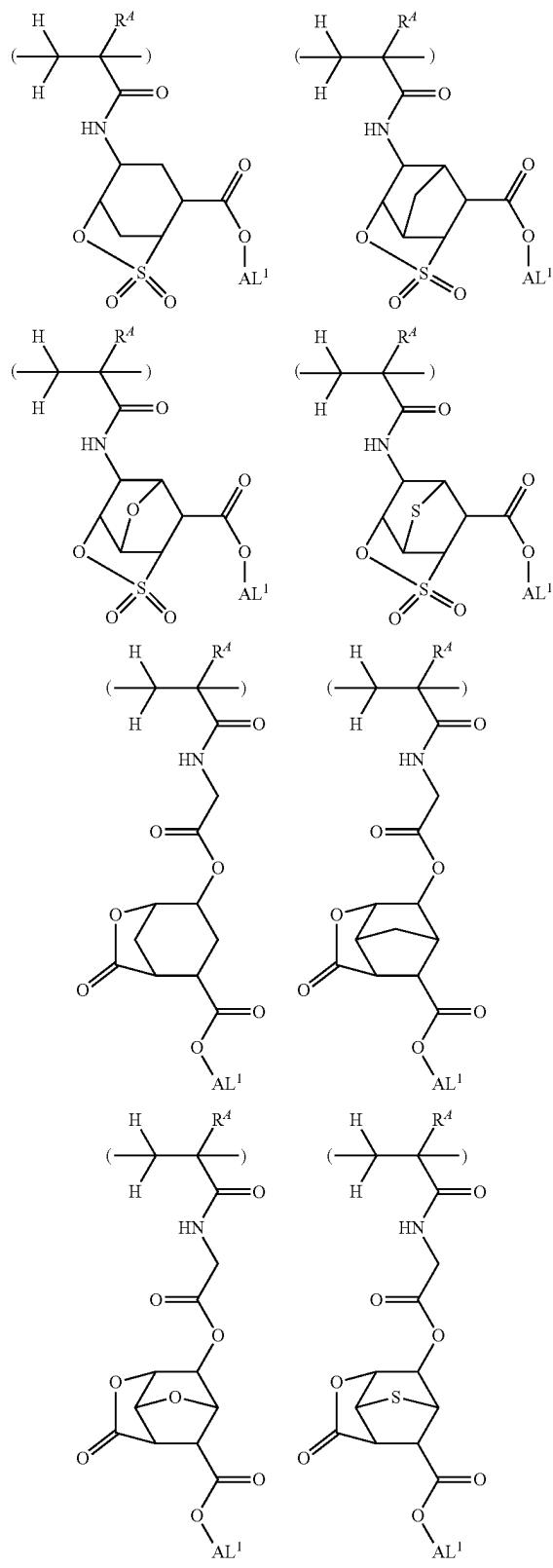
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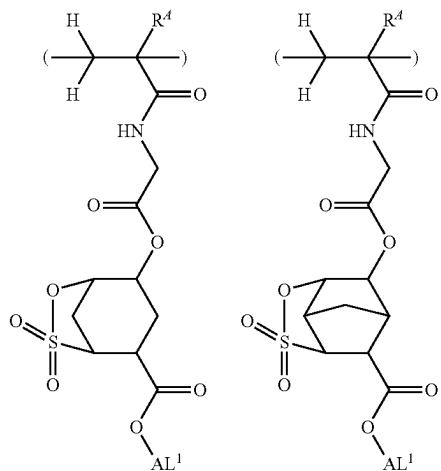
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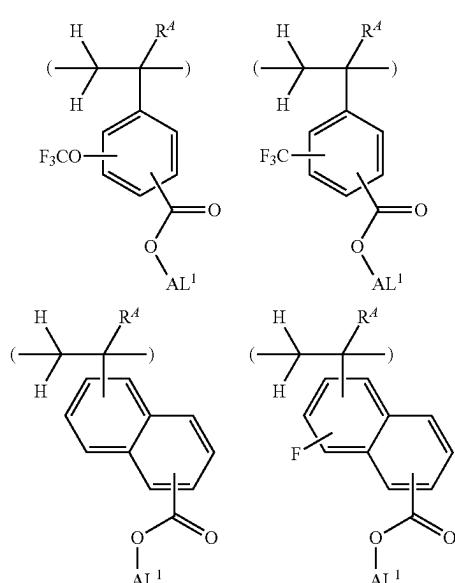
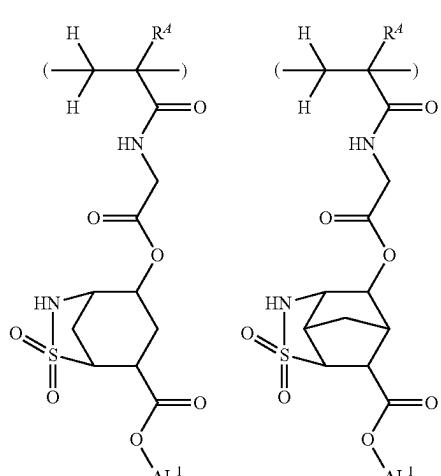
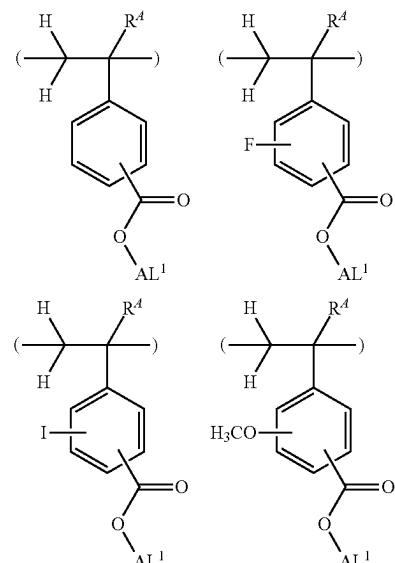
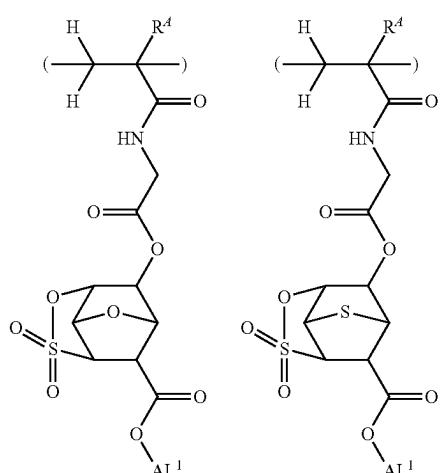
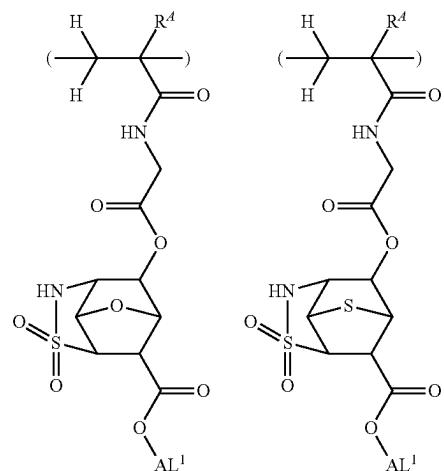
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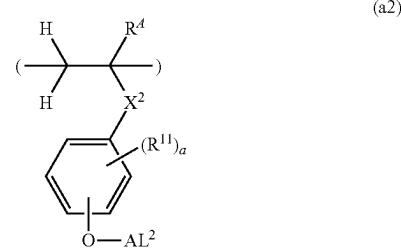
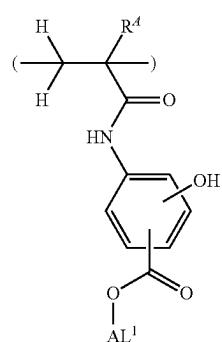
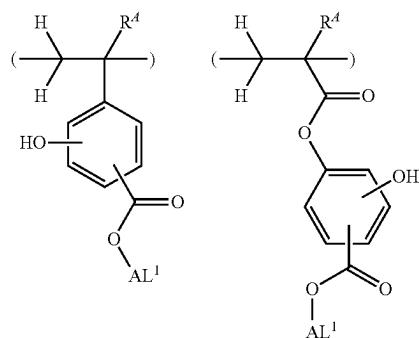
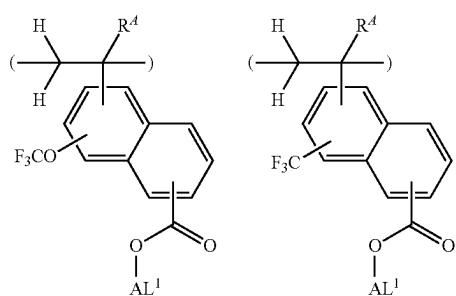
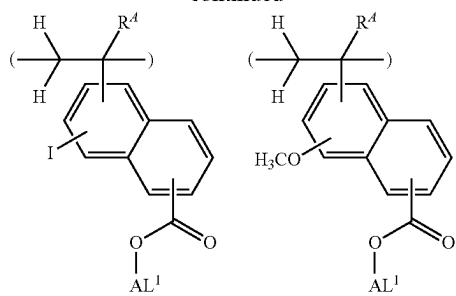
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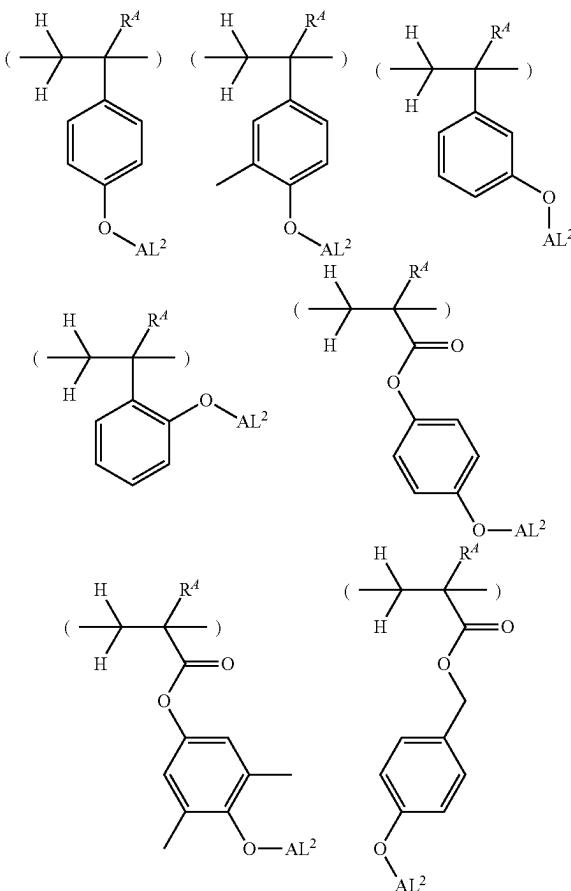


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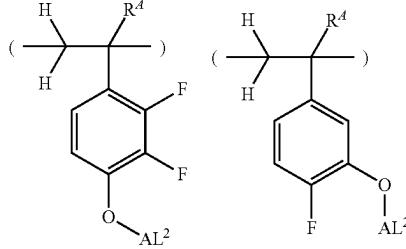
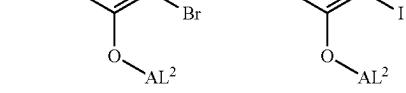
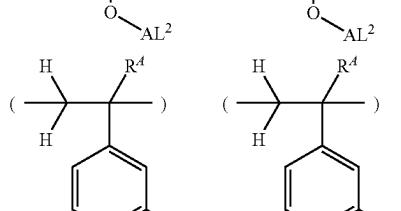
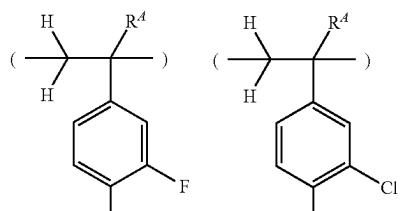
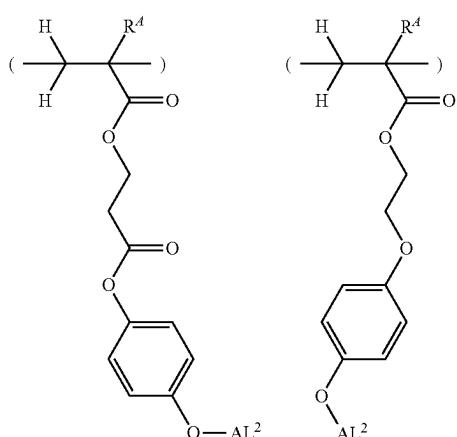
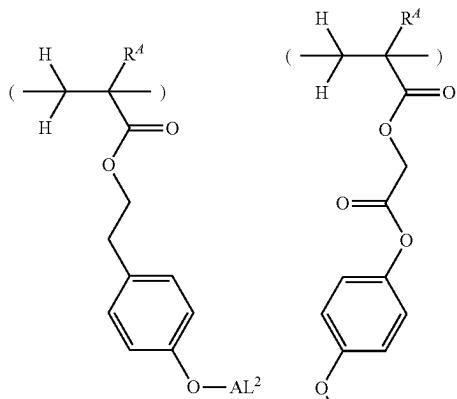
[0177] In formula (a2), R^A is hydrogen, fluorine, methyl or trifluoromethyl. X^2 is a single bond or $*-C(=O)-O-$ wherein * designates a point of attachment to the carbon atom in the backbone. R^{11} is halogen, cyano, a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, a C_1-C_{20} hydrocarboxy group which may contain a heteroatom, a C_2-C_{20} hydrocarblycarbonyl group which may contain a heteroatom, a C_2-C_{20} hydrocarblycarbonyloxy group which may contain a heteroatom, or a C_2-C_{20} hydrocarblyoxycarbonyl group which may contain a heteroatom. AL^2 is an acid labile group, examples of which are as exemplified for the acid labile group AL^1 . The subscript "a" is an integer of 0 to 4, preferably 0 or 1.

[0178] Examples of the repeat unit (a2) are shown below, but not limited thereto. Herein R^A and AL^2 are as defined above.

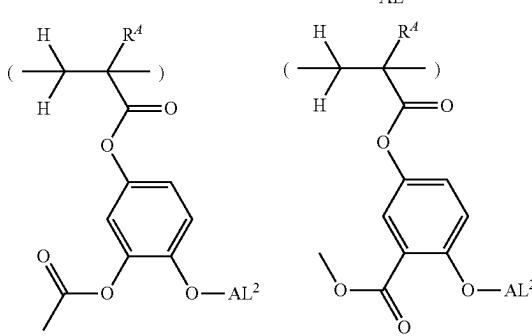
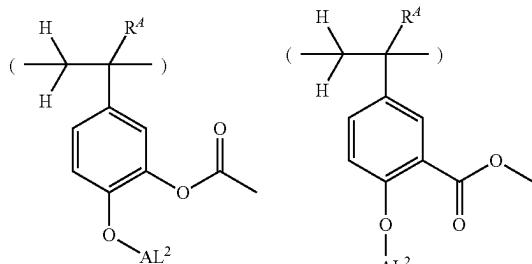
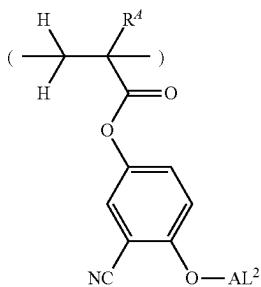
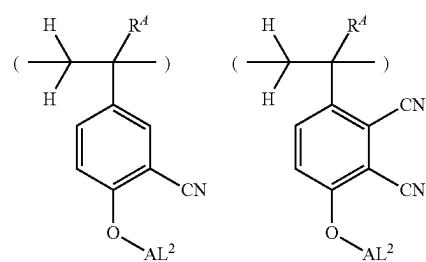
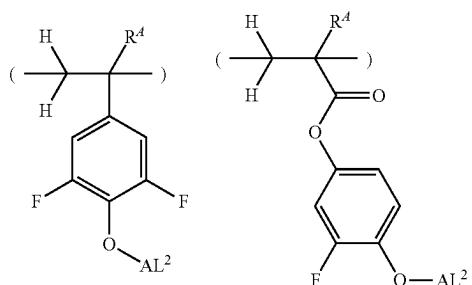


[0176] The base polymer (B) may further contain repeat units having the formula (a2), which are also referred to as repeat units (a2).

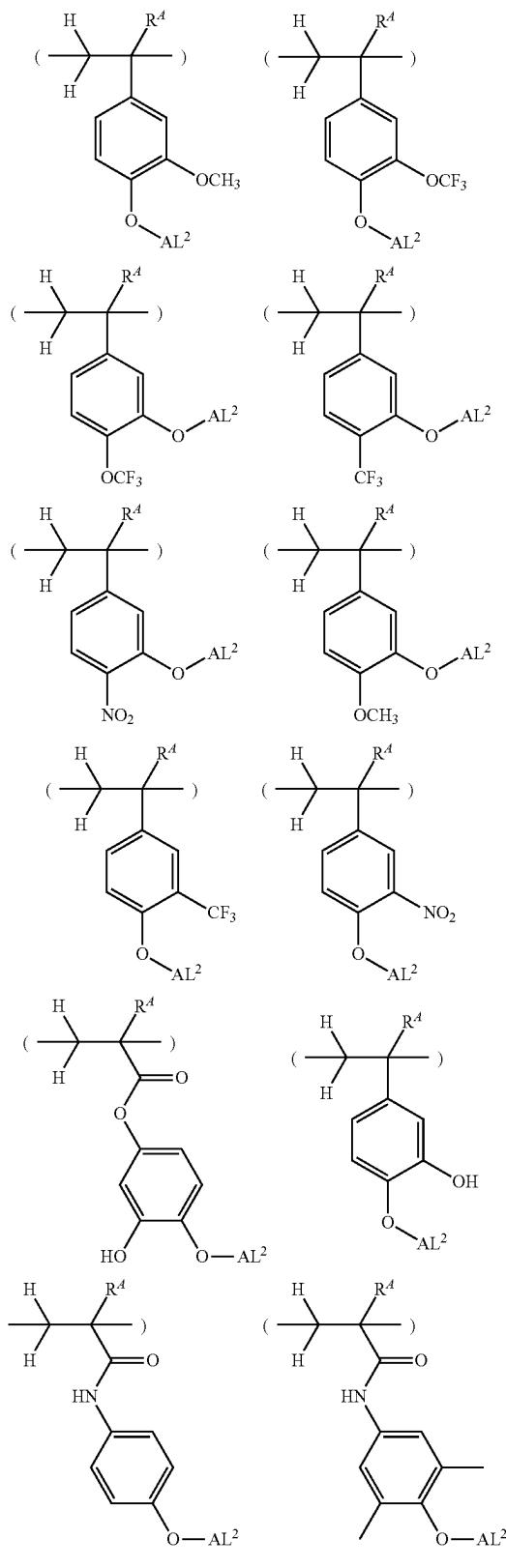
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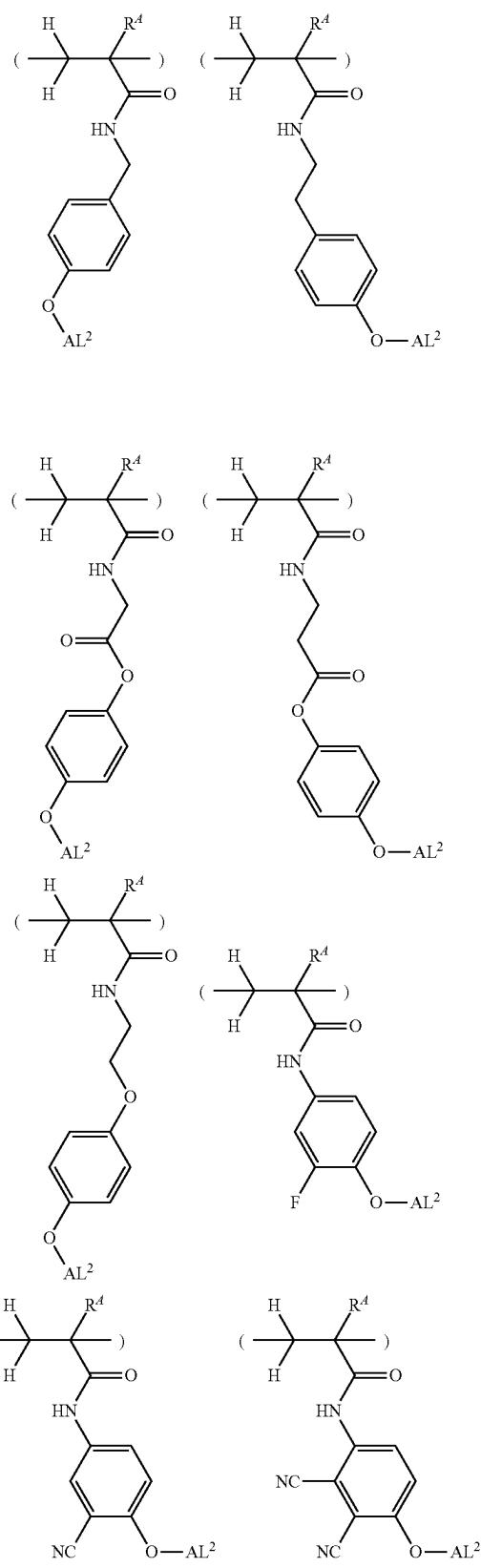
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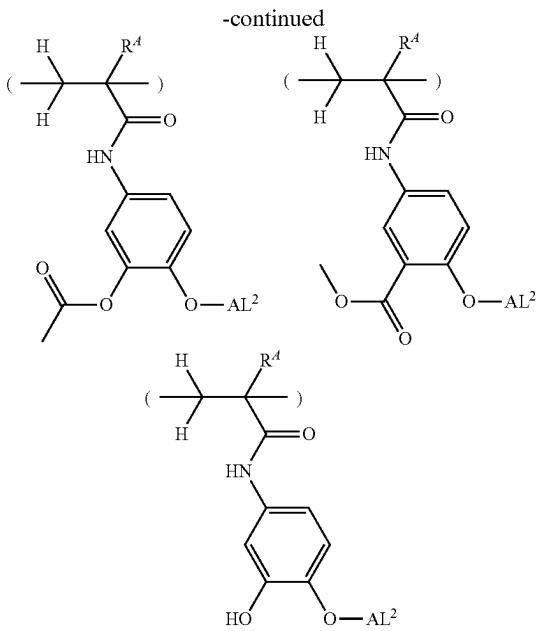


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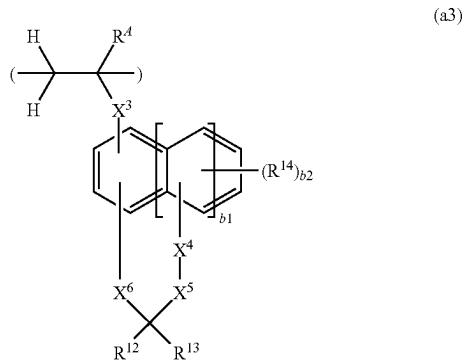


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[0179] In a preferred embodiment, the base polymer further comprises repeat units having the formula (a3), which are simply referred to as repeat units (a3).



[0180] In formula (a3), b1 is 0 or 1. The relevant structure is a benzene ring in case of b1=0, and a naphthalene ring in case of b1=1. The benzene ring corresponding to b1=0 is preferred from the standpoint of solvent solubility. The subscript b2 is an integer of 0 to 3 in case of b1=0 and an integer of 0 to 5 in case of b1=1. It is preferred from the standpoint of availability of reactants that b2 be 0, 1, 2 or 3, more preferably 0, 1 or 2.

[0181] In formula (a3), R^A is hydrogen, fluorine, methyl or trifluoromethyl, preferably hydrogen or methyl, more preferably hydrogen.

[0182] In formula (a3), X^3 is a single bond, *-C(=O)-O- or *-C(=O)-NH-, wherein * designates a point of attachment to the carbon atom in the backbone. X^3 is preferably a single bond or *-C(=O)-O-, more preferably a single bond.

[0183] In formula (a3), R^12 and R^13 are each independently hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be sat-

rated or unsaturated and straight, branched or cyclic. Examples thereof include C₁-C₂₀ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, n-hexyl, n-octyl, n-nonyl, n-decyl, undecyl, dodecyl, tridecyl, tetradecyl, pentadecyl, heptadecyl, octadecyl, nonadecyl and icosyl; C₃-C₂₀ cyclic saturated hydrocarbyl groups such as cyclopropyl, cyclopentyl, cyclohexyl, cyclopropylmethyl, 4-methylcyclohexyl, cyclohexylmethyl, norbornyl, and adamantly; C₂-C₂₀ alkenyl groups such as vinyl, allyl, propenyl, butenyl, and hexenyl; C₃-C₂₀ cyclic unsaturated hydrocarbyl groups such as cyclohexenyl; C₆-C₂₀ aryl groups such as phenyl and naphthyl; C₇-C₂₀ aralkyl groups such as benzyl, 1-phenylethyl, and 2-phenylethyl, and combinations thereof. In the hydrocarbyl group, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some -CH₂- may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (-C(=O)-O-C(=O)-) or haloalkyl moiety.

[0184] Also, R¹² and R¹³ may bond together to form a ring with the carbon atom to which they are attached. Exemplary rings include cyclopropane, cyclobutane, cyclopentane, cyclohexane, norbornane, and adamantan rings. In the ring, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some -CH₂- may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the ring may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (-C(=O)-O-C(=O)-) or haloalkyl moiety.

[0185] In formula (a3), R¹⁴ is halogen, hydroxy, cyano, nitro, a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbyloxy group which may contain a heteroatom, a C₂-C₂₀ hydrocarbyloxycarbonyl group which may contain a heteroatom, a C₁-C₂₀ hydrocarbylthio group which may contain a heteroatom, or -N(R^{14A})(R^{14B}). R^{14A} and R^{14B} are each independently hydrogen or a C₁-C₆ hydrocarbyl group. Suitable halogen atoms include fluorine, chlorine, bromine and iodine, with fluorine and iodine being preferred. The hydrocarbyl group and hydrocarbyl moiety in the hydrocarbyloxy, hydrocarbyloxycarbonyl and hydrocarbylthio groups may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for the hydrocarbyl groups R¹² and R¹³. In the hydrocarbyl group, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some -CH₂- may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (-C(=O)-O-C(=O)-) or haloalkyl moiety. When b2 is 2 or more, a plurality of R¹⁴ may be identical or different.

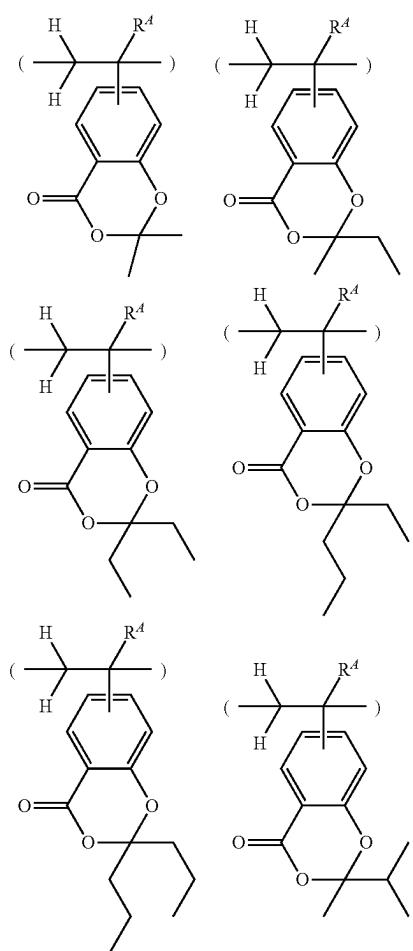
[0186] When b2 is 2 or more, a plurality of R¹⁴ may bond together to form a ring with the carbon atoms on the aromatic ring to which they are attached. Exemplary rings

include cyclopropane, cyclobutane, cyclopentane, cyclohexane, norbornane, and adamantane rings. In the ring, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some —CH₂— may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the ring may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (—C(=O)—O—C(=O)—) or haloalkyl moiety.

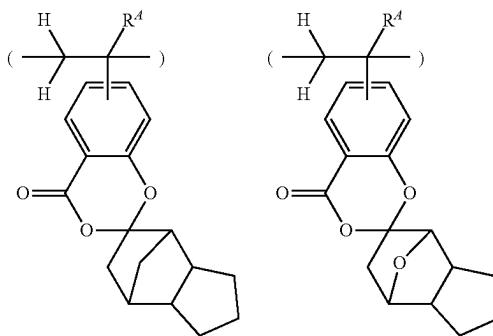
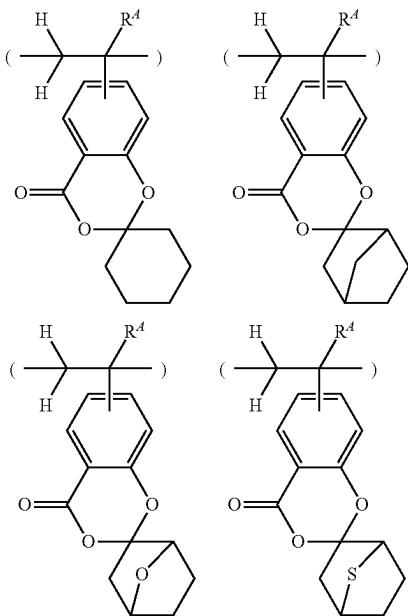
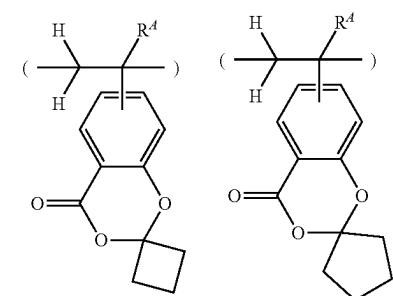
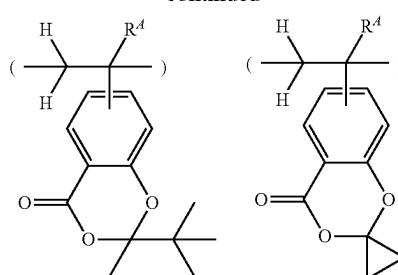
[0187] In formula (a3), X⁴ is a single bond, C₁-C₄ aliphatic hydrocarbylene group, carbonyl group, sulfonyl group, or a group obtained by combining the foregoing. It is preferred from the aspect of reactant availability that X⁴ be a single bond, carbonyl group or sulfonyl group. It is more preferred from the aspect of a polar group created after reaction that X⁴ be a single bond or carbonyl group.

[0188] In formula (a3), X⁵ and X⁶ are each independently oxygen or sulfur. Notably, X⁴ and X⁶ are bonded to vicinal carbon atoms on the aromatic ring. X⁵ and X⁶ may be identical or different. It is preferred from the aspect of reactivity that X⁵ and X⁶ be both oxygen.

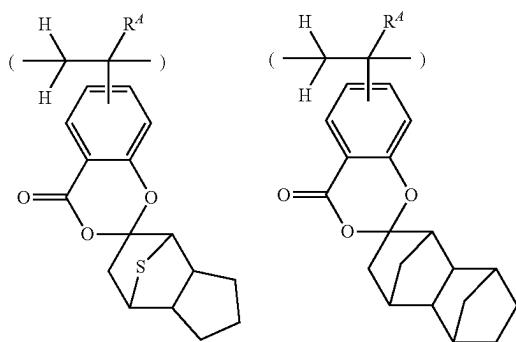
[0189] Examples of the repeat unit (b3) are shown below, but not limited thereto. Herein R^A is as defined above. The bond positions of substituents on the aromatic ring are interchangeable.



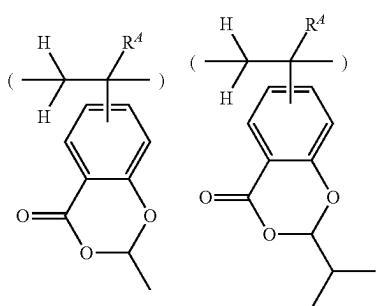
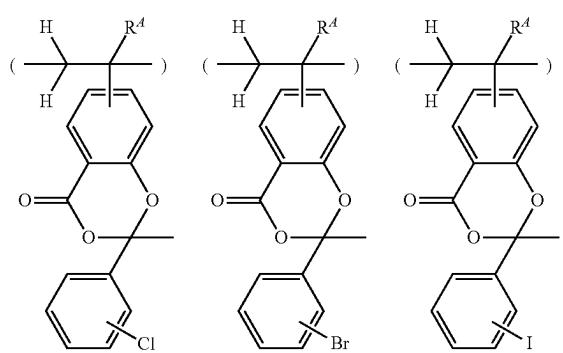
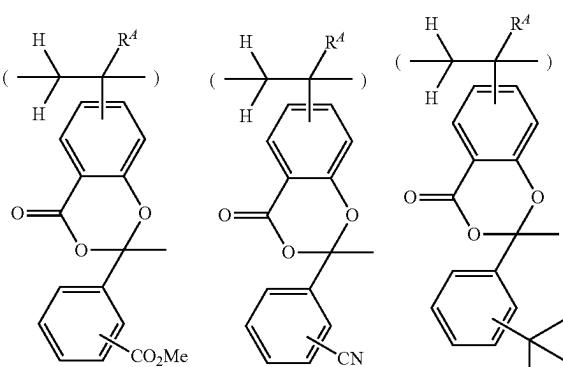
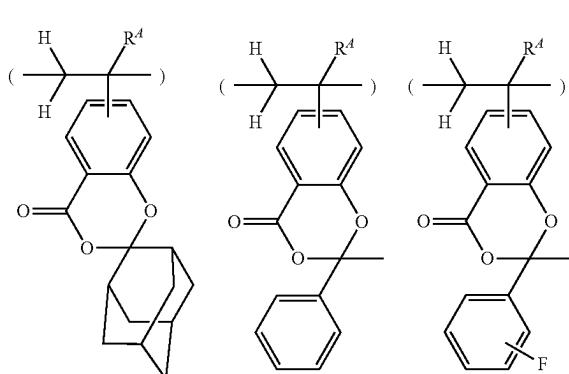
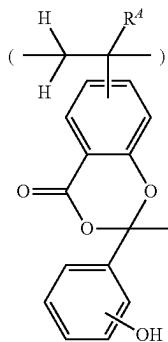
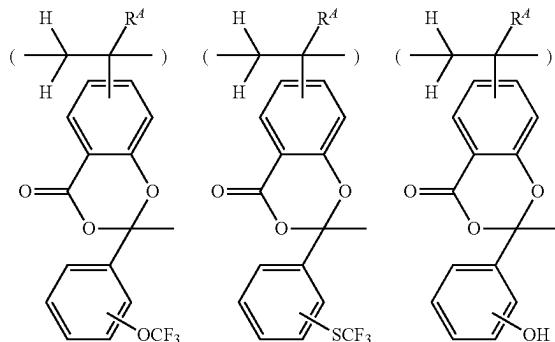
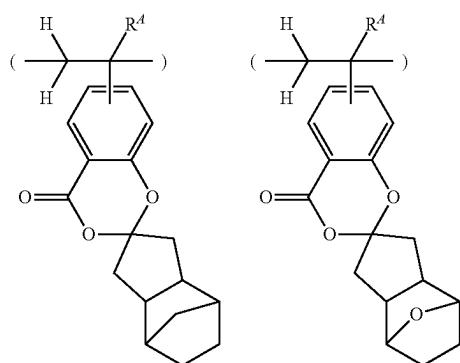
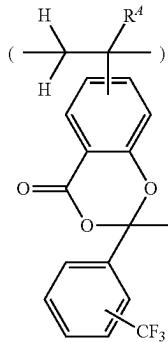
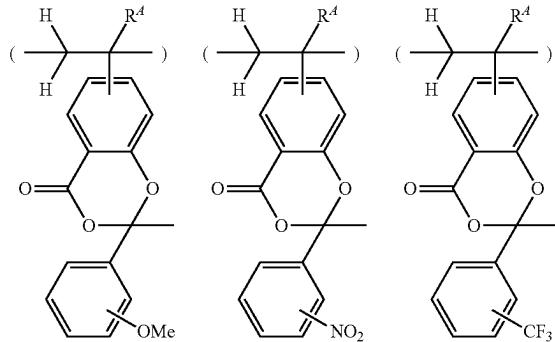
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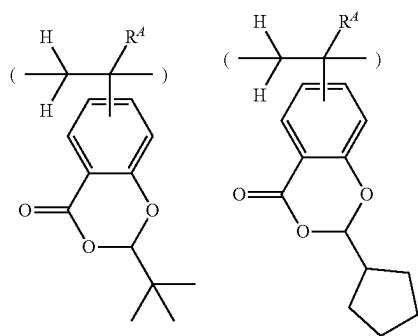
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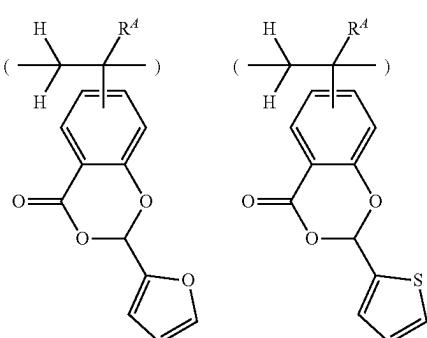
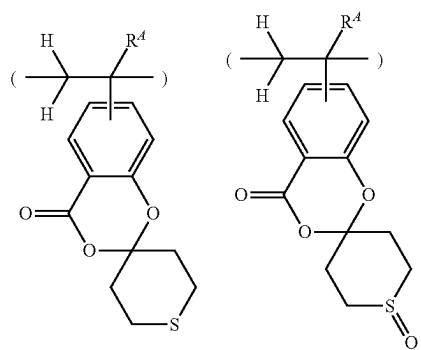
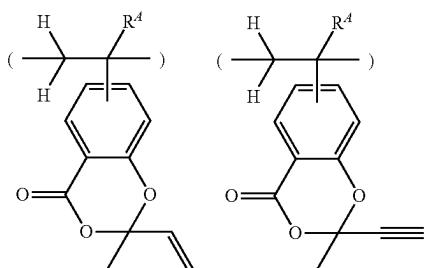
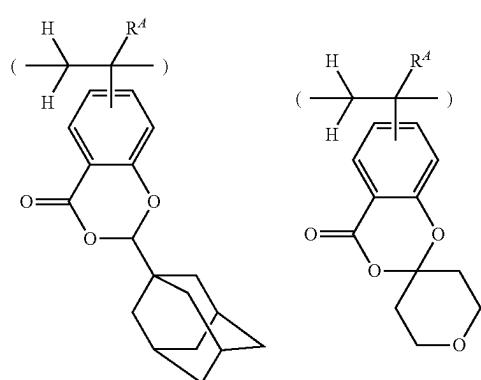
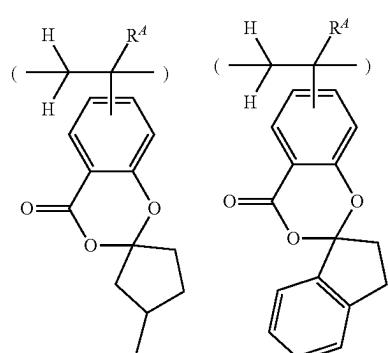
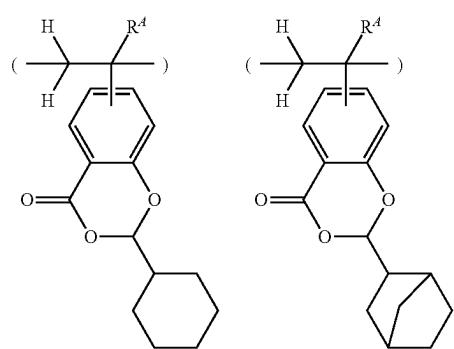
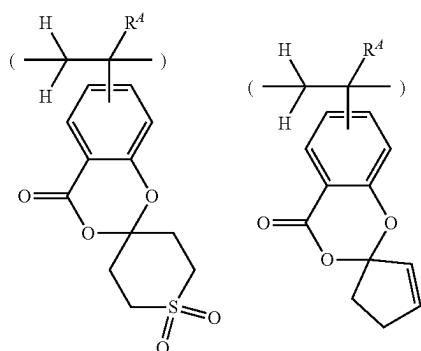
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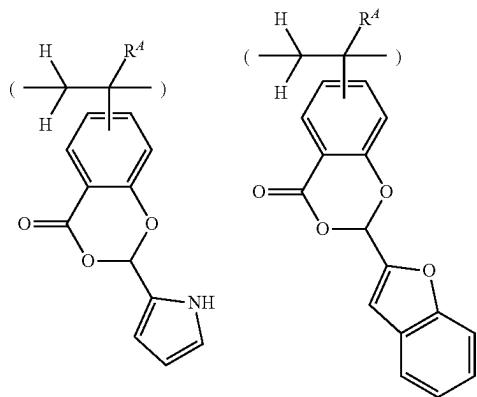
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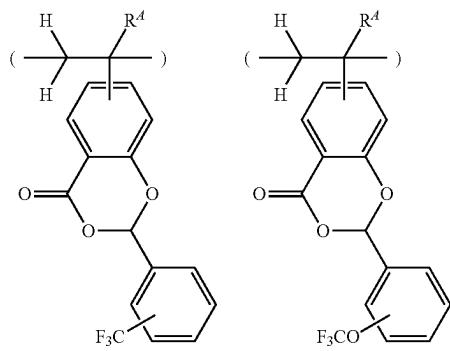
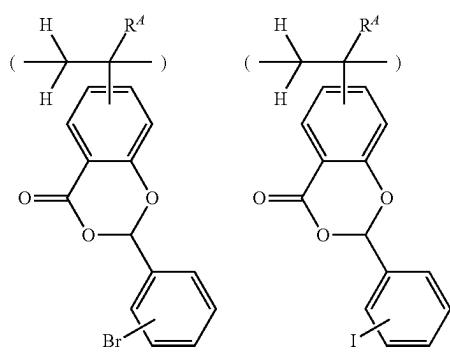
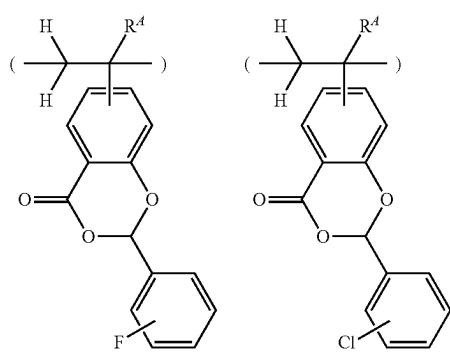
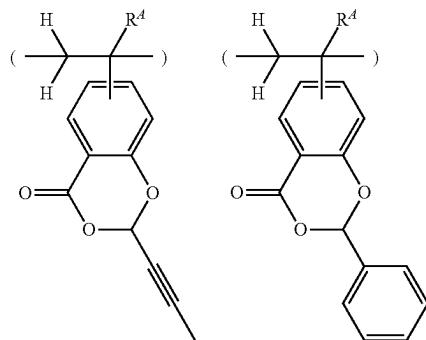
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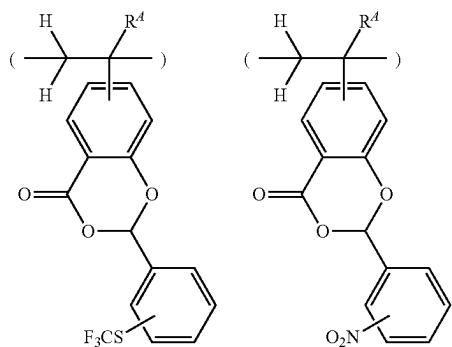
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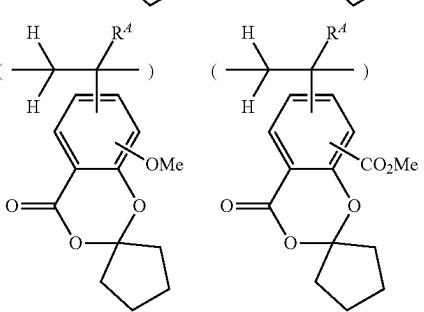
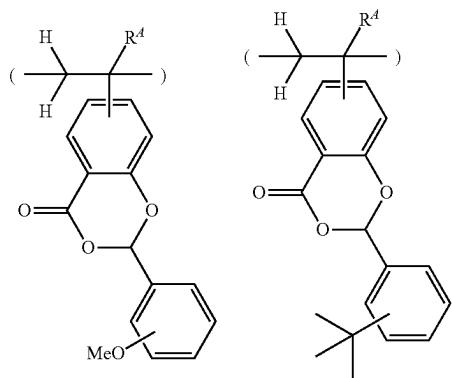
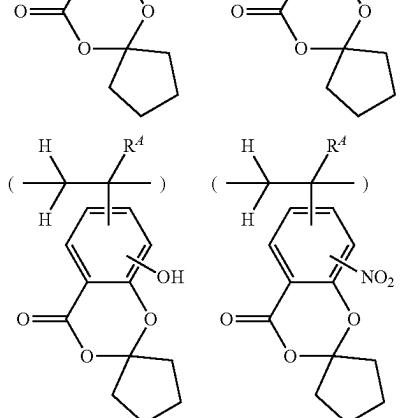
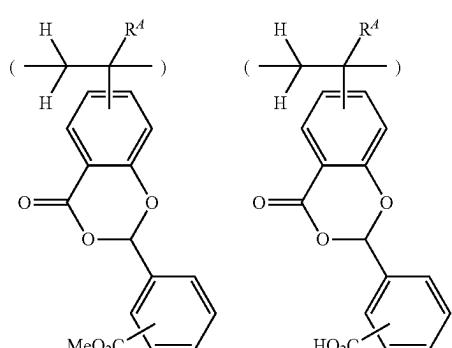
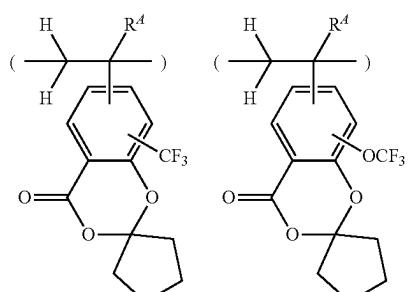
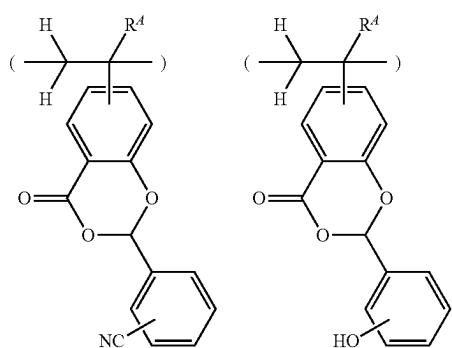
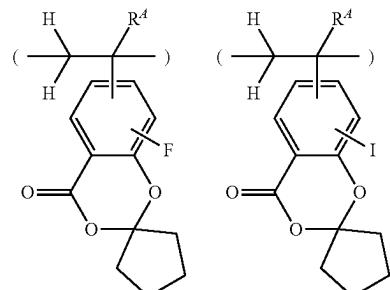
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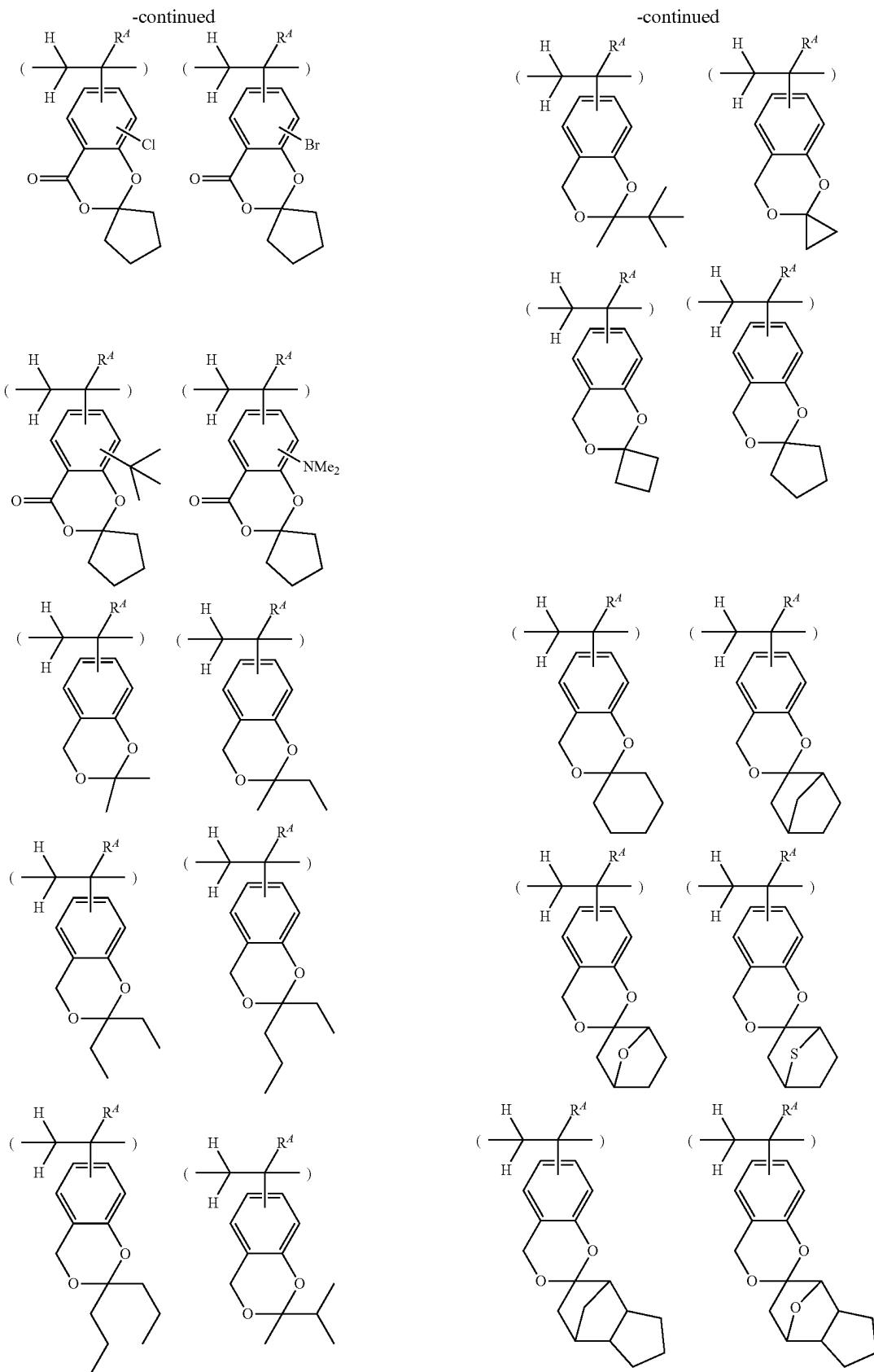


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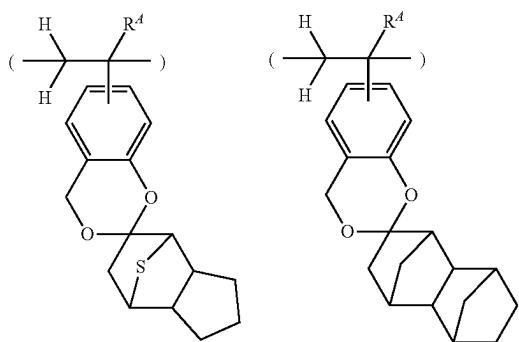


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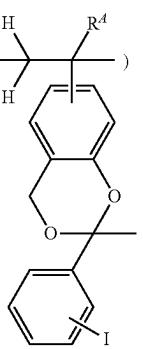
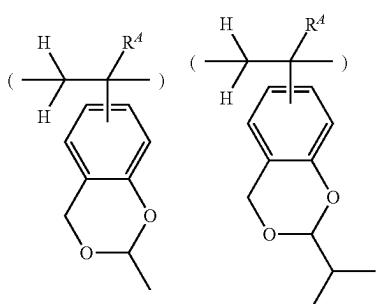
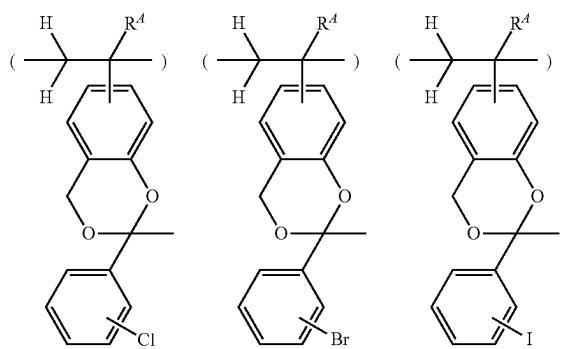
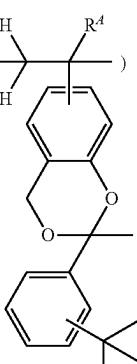
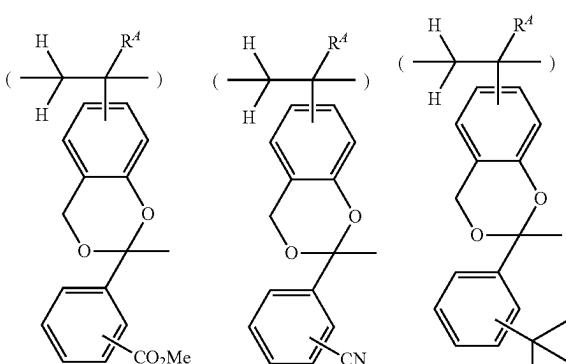
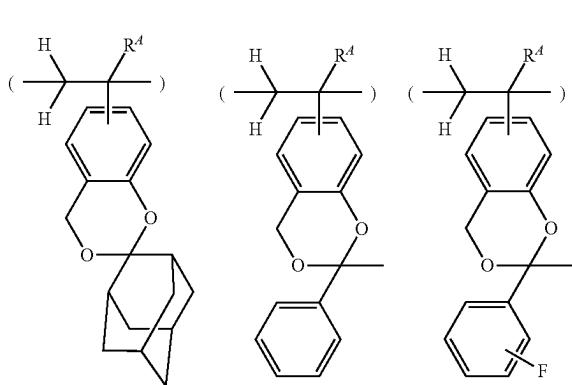
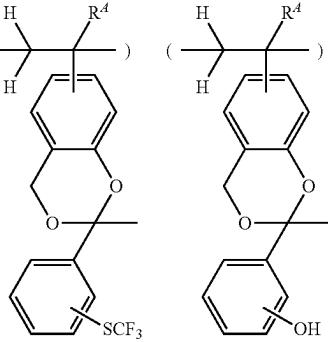
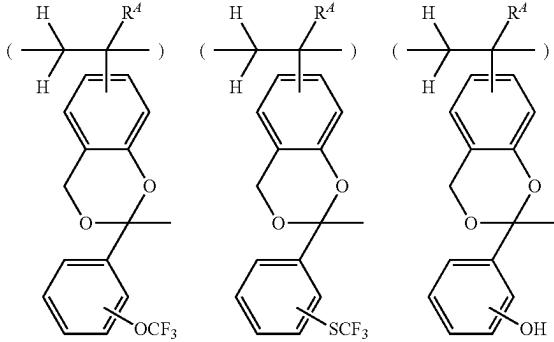
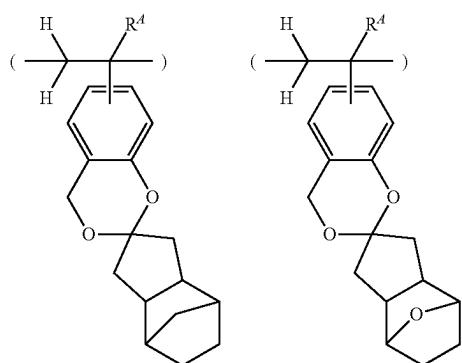
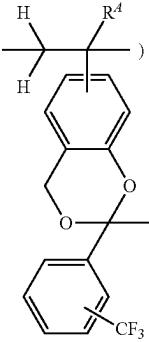
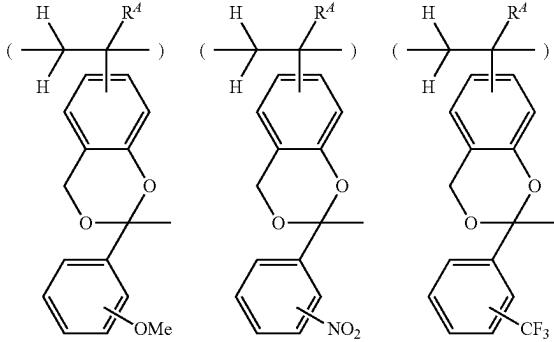




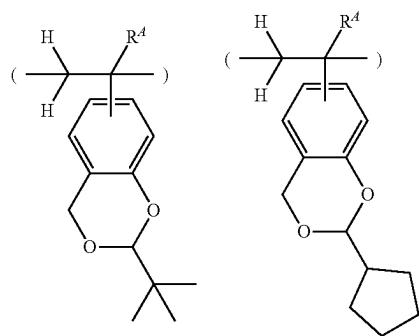
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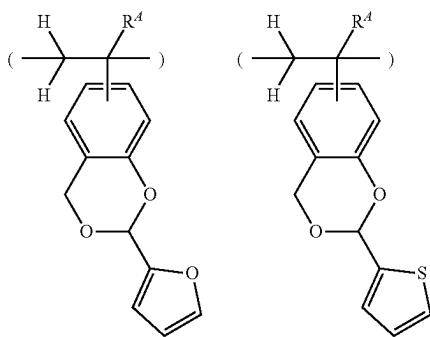
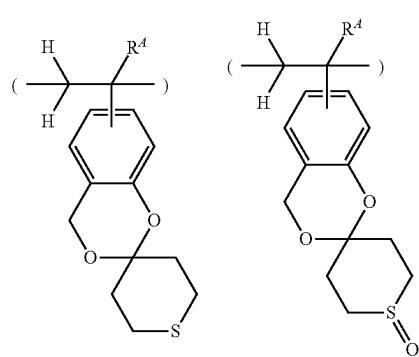
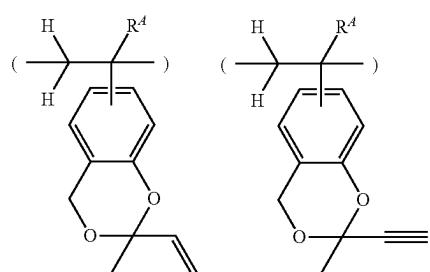
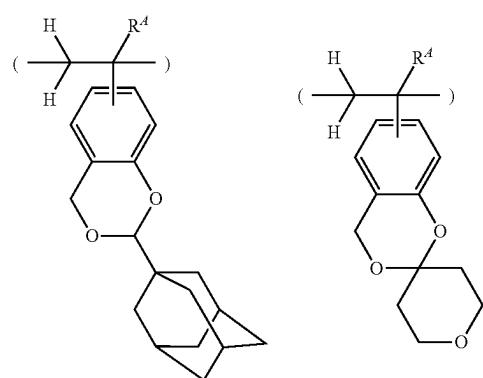
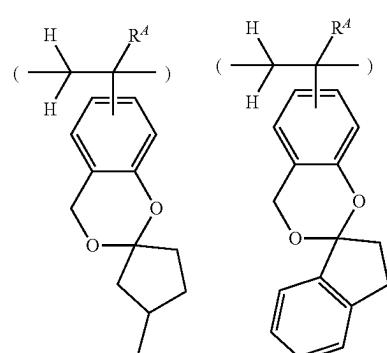
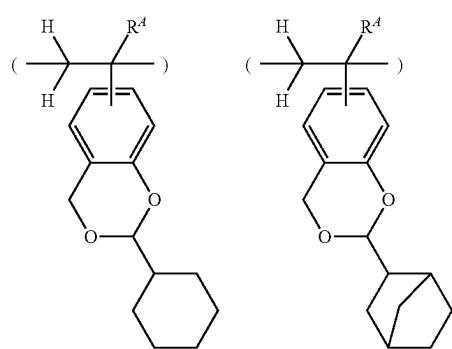
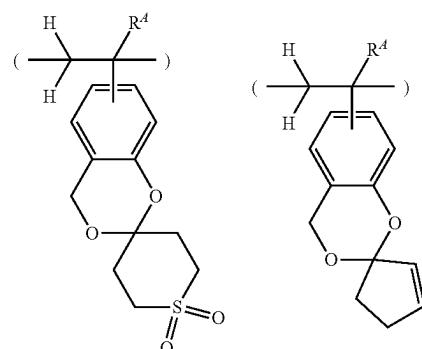
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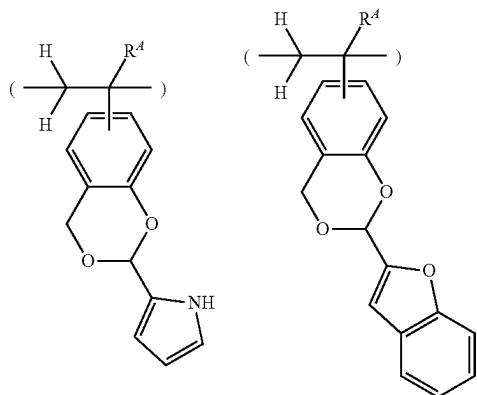
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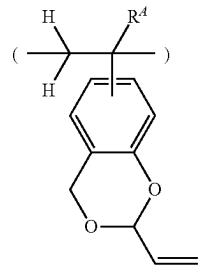
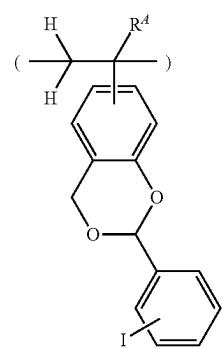
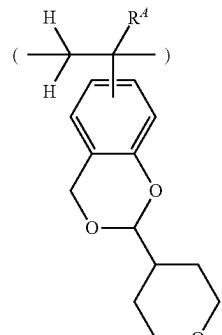
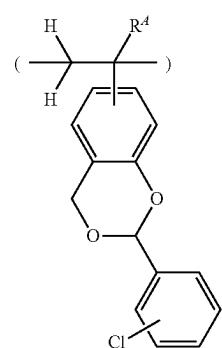
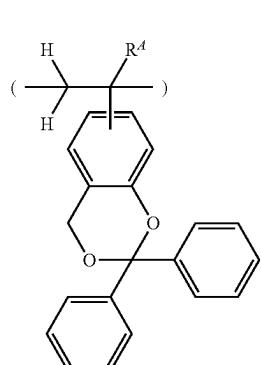
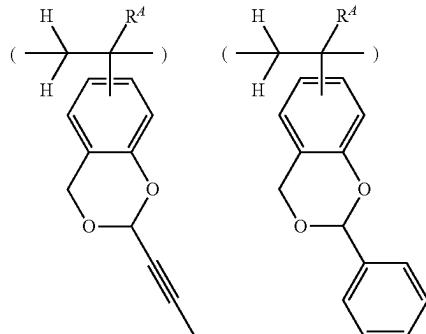
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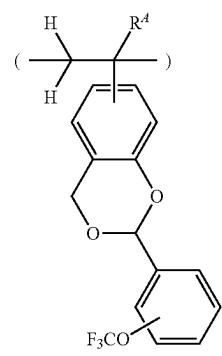
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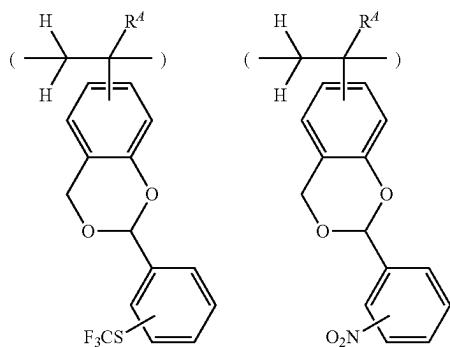
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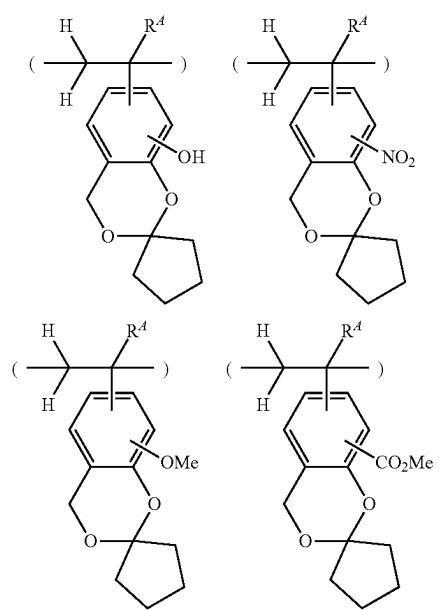
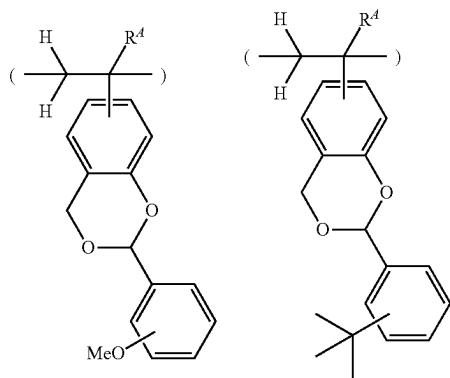
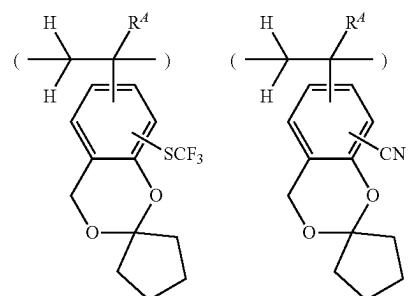
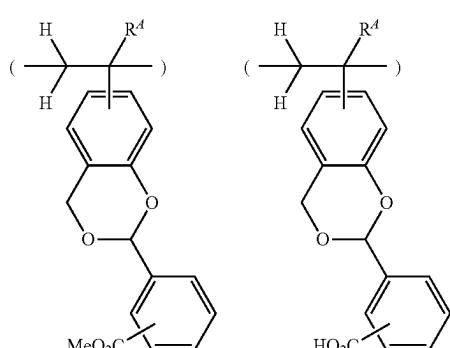
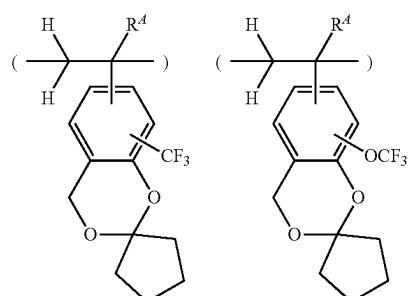
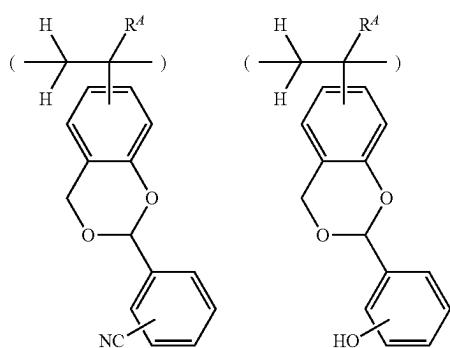
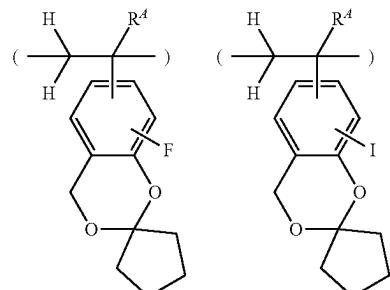
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 & & \text{C}_6\text{H}_4 \\
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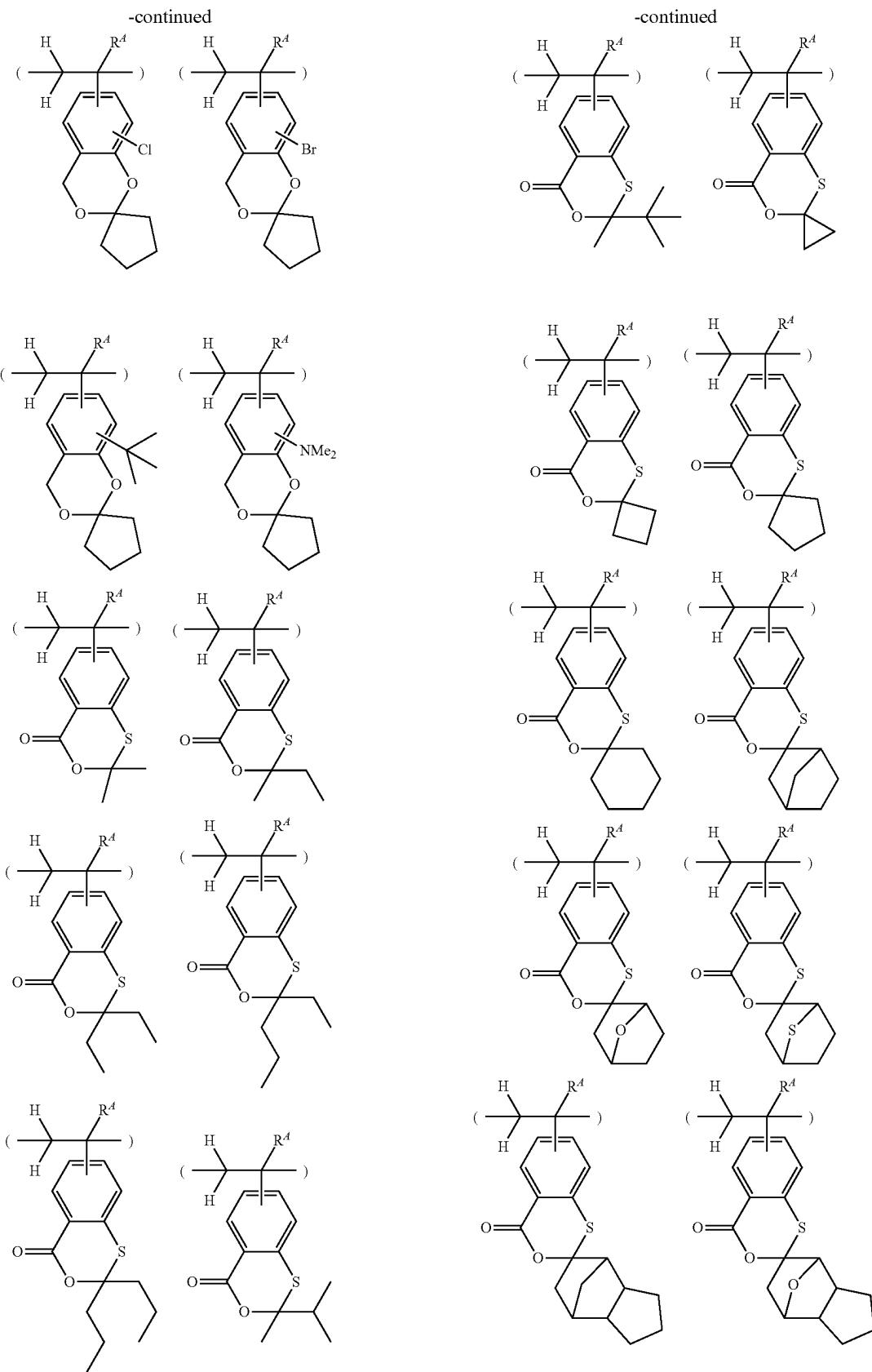


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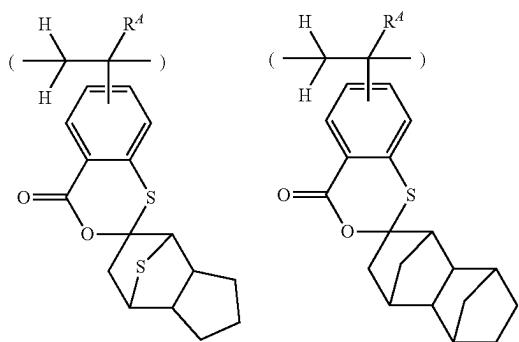


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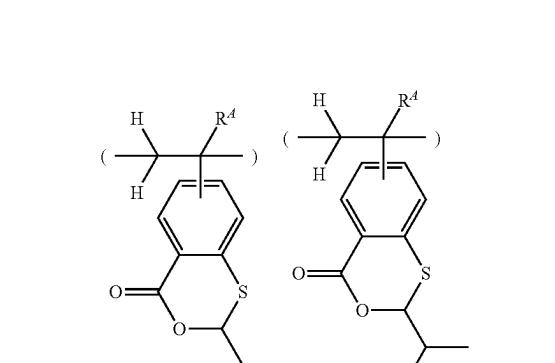
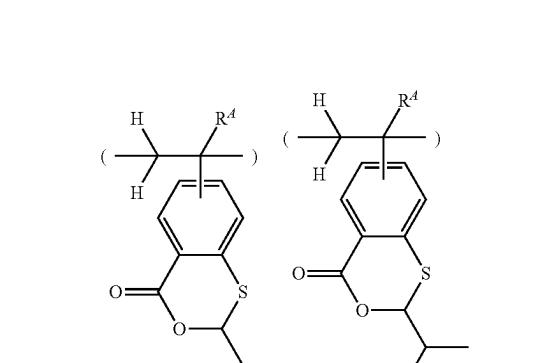
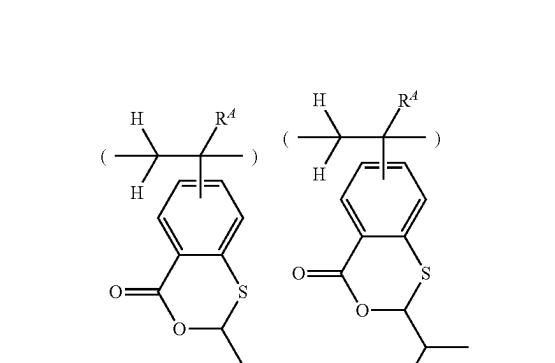
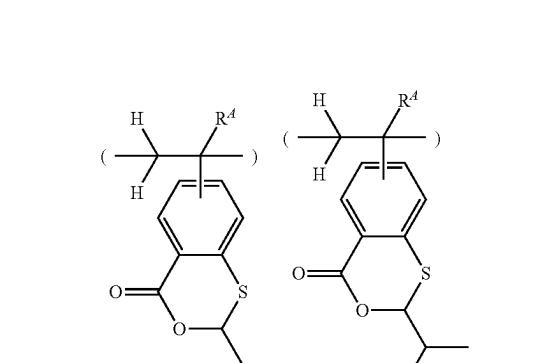
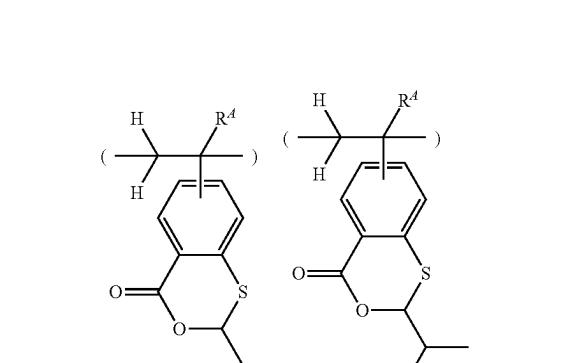
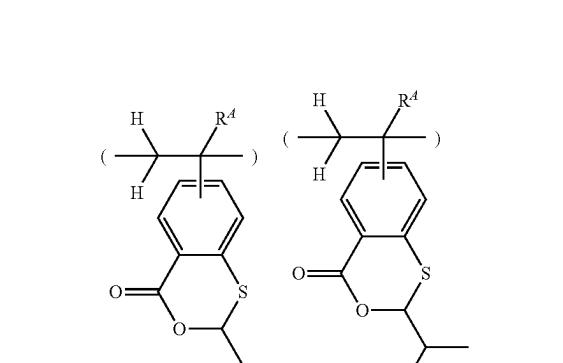
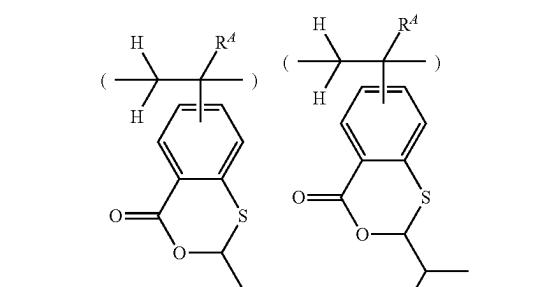
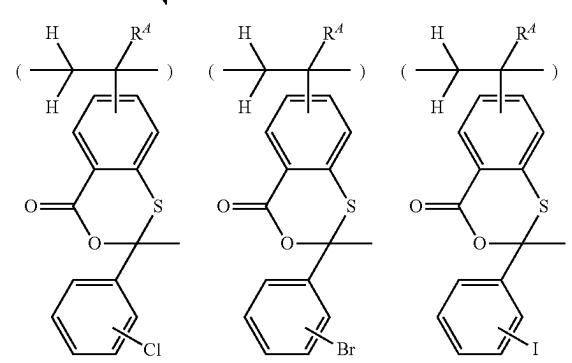
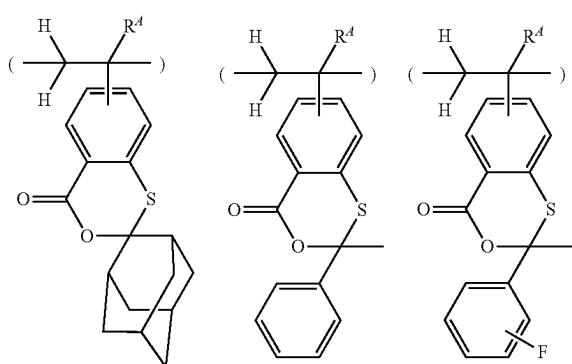
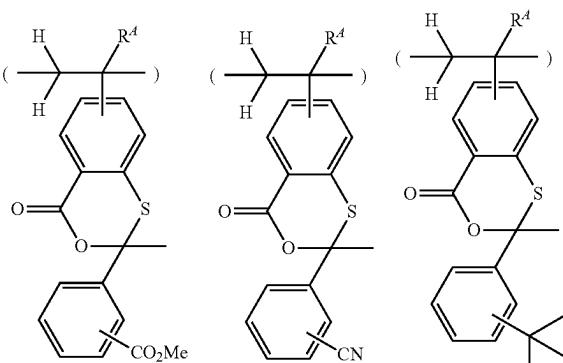
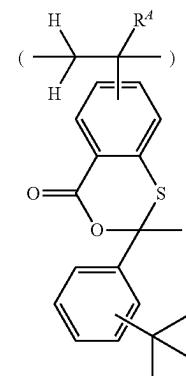
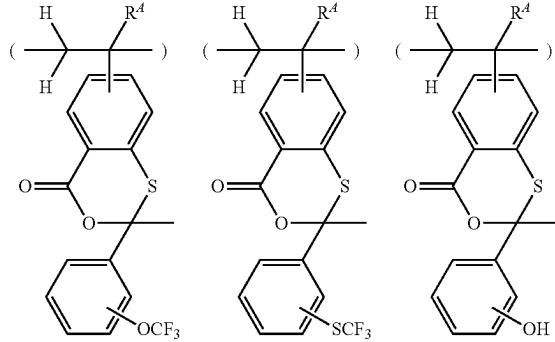
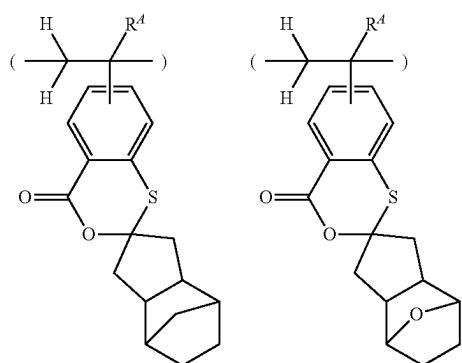
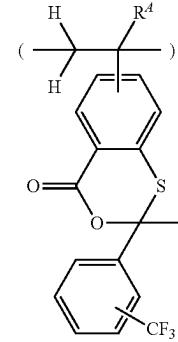
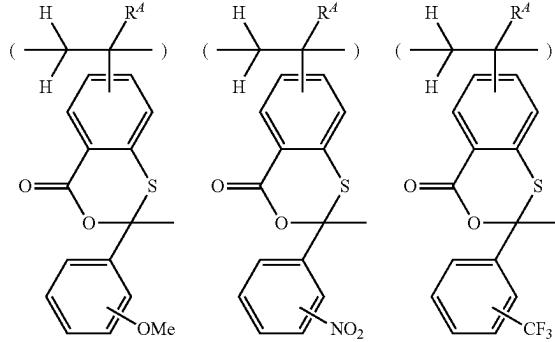




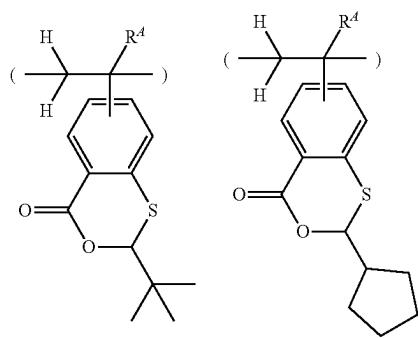
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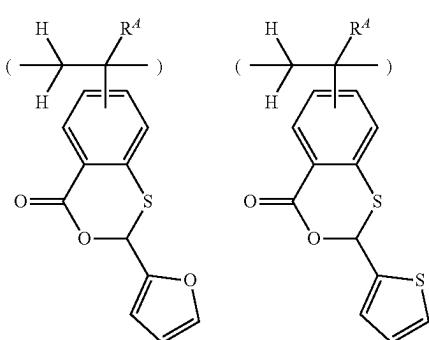
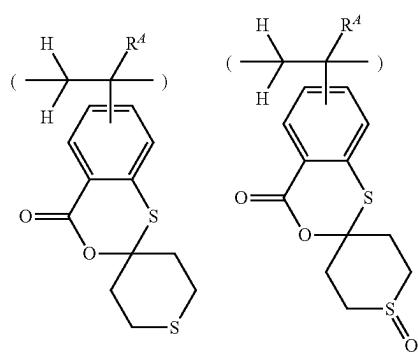
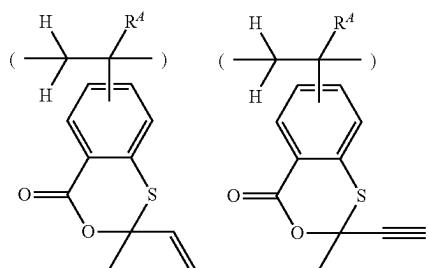
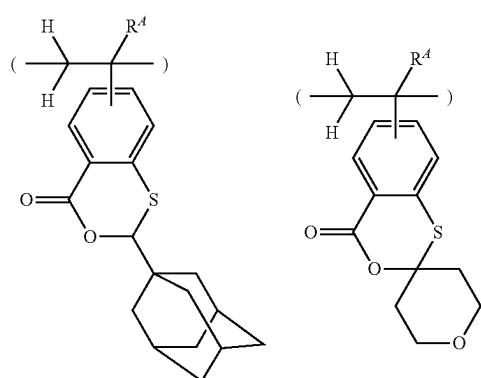
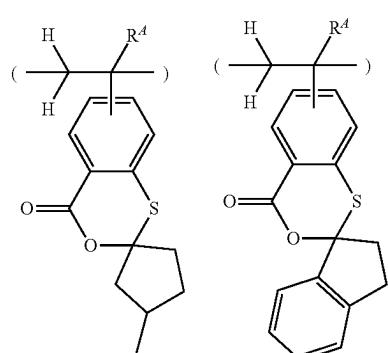
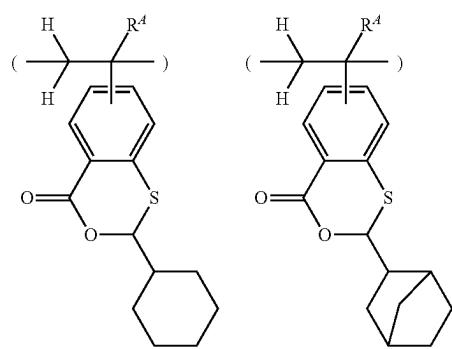
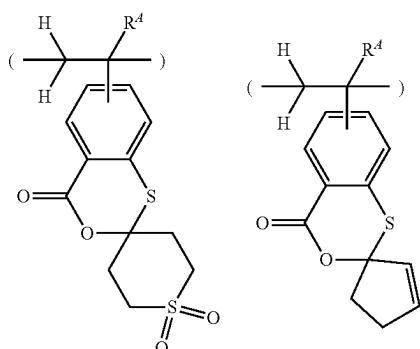
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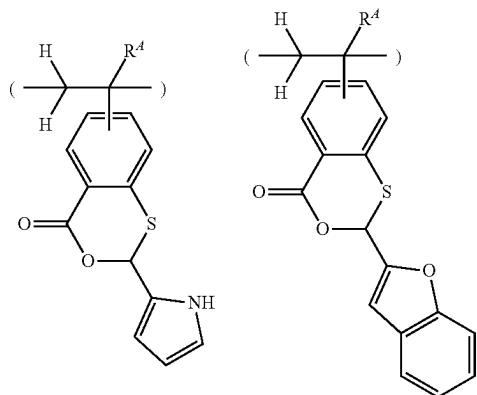
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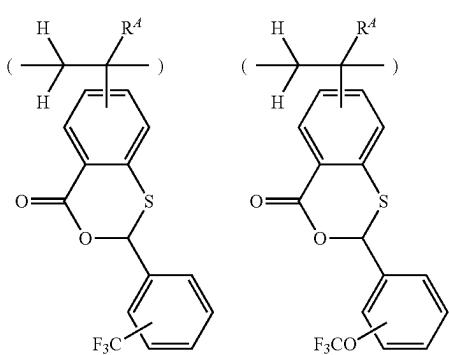
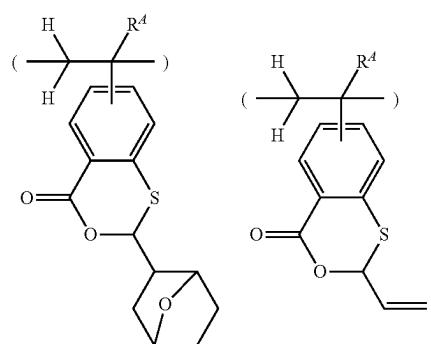
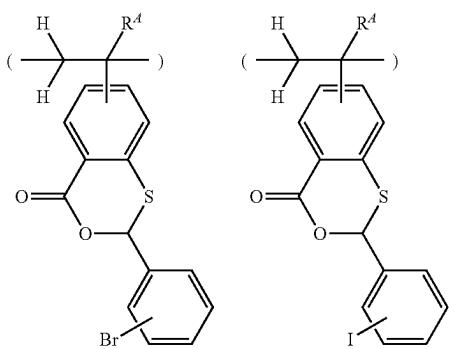
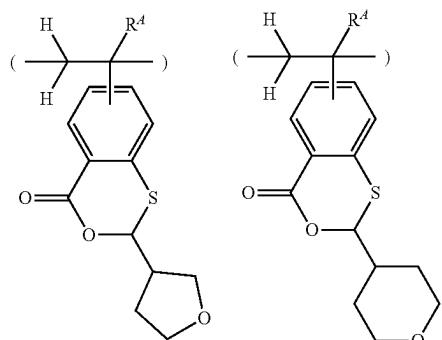
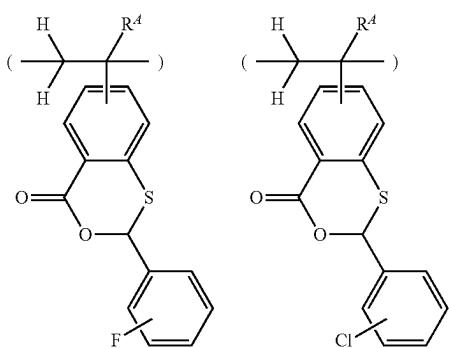
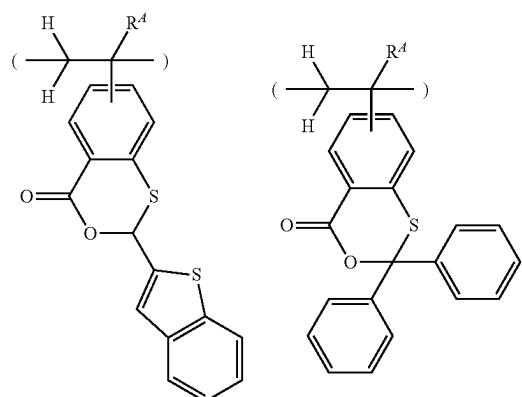
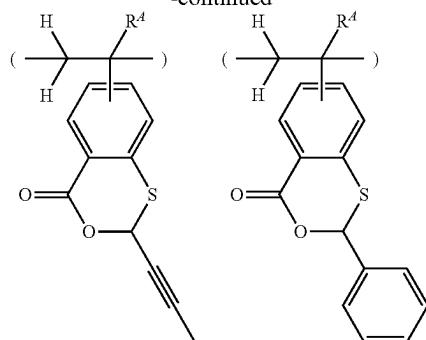
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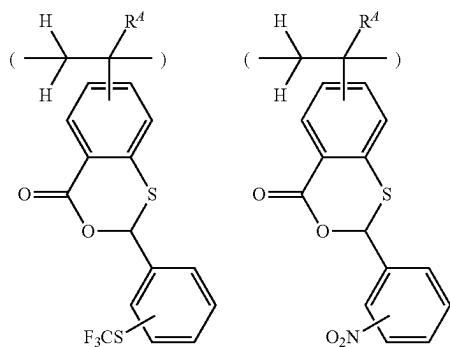
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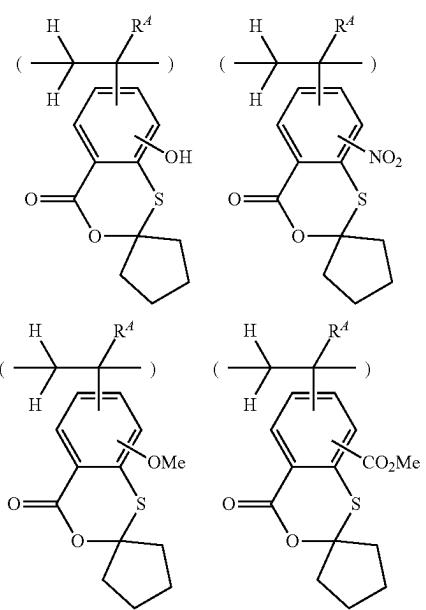
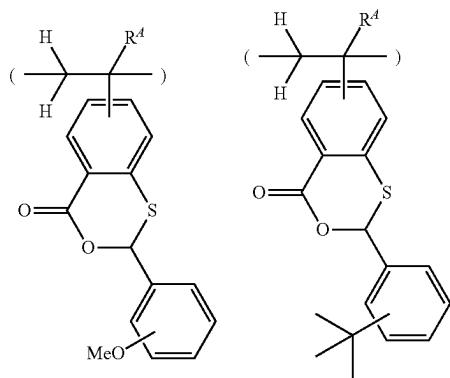
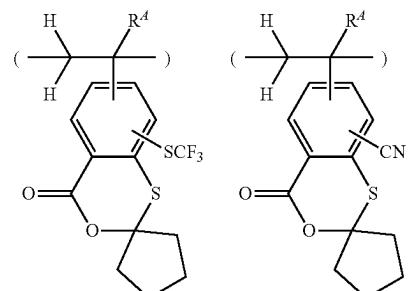
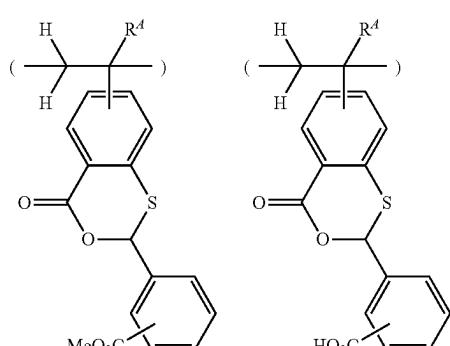
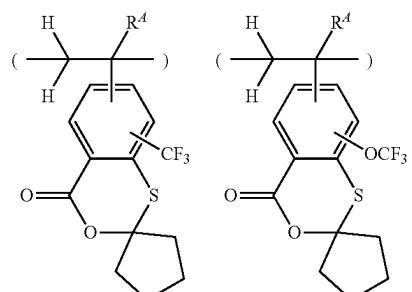
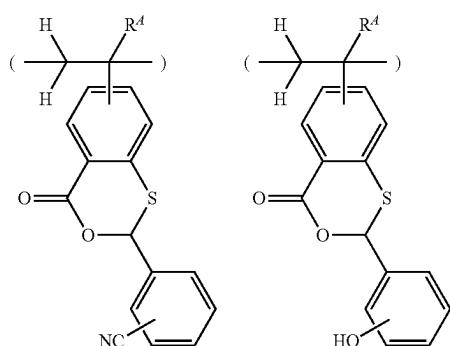
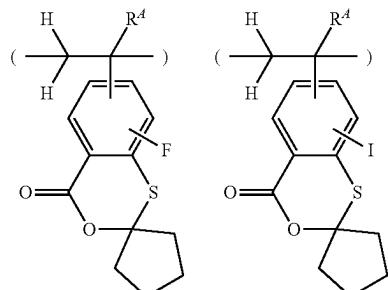
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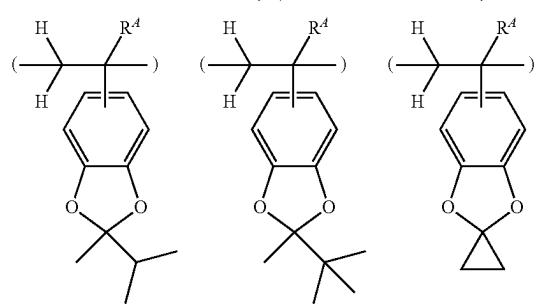
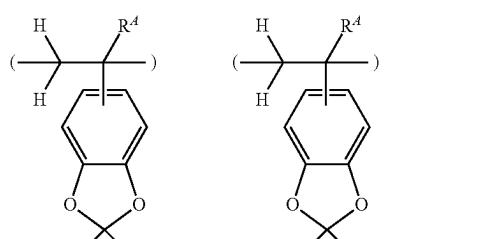
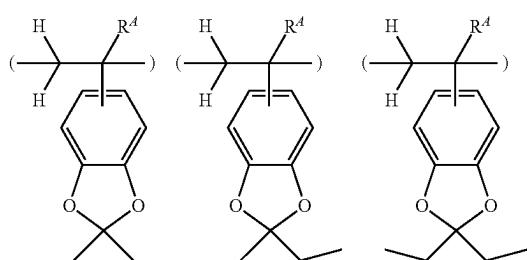
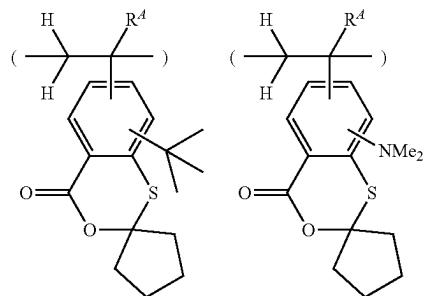
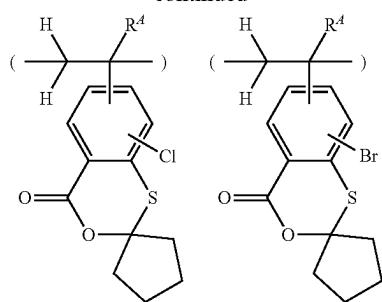
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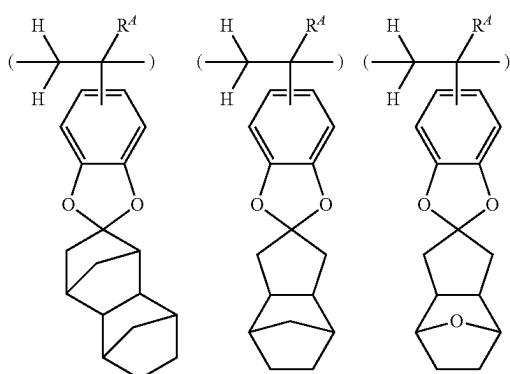
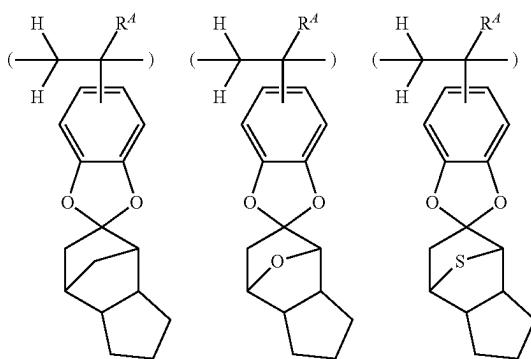
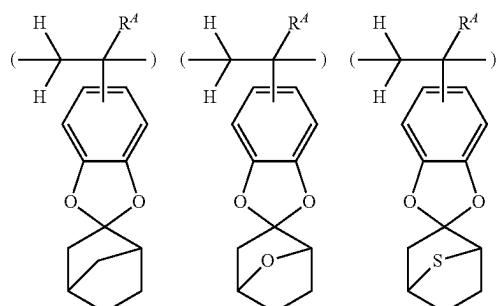
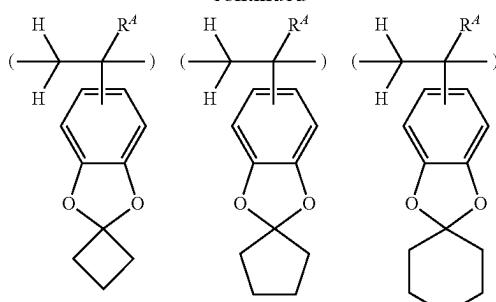
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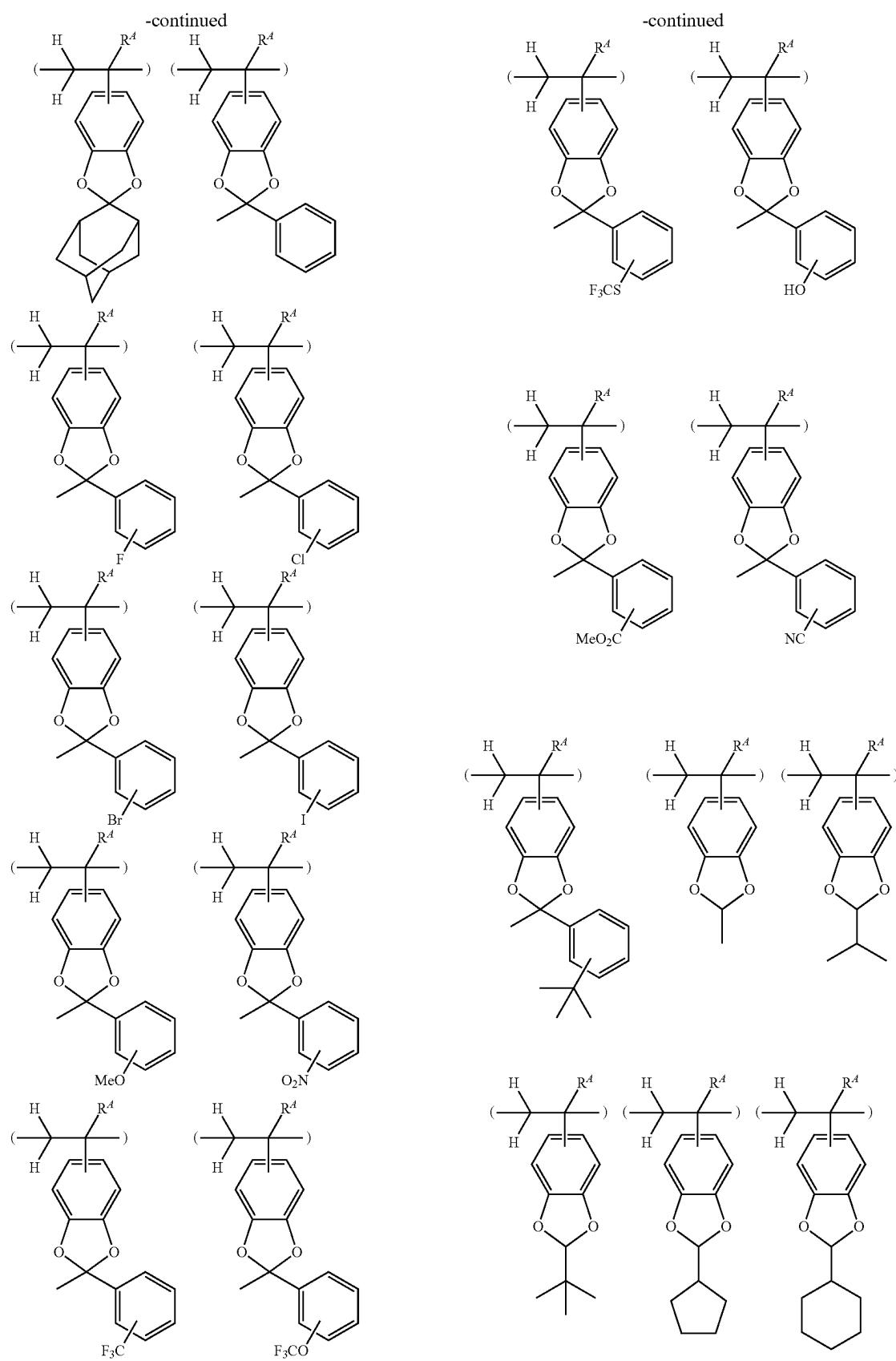


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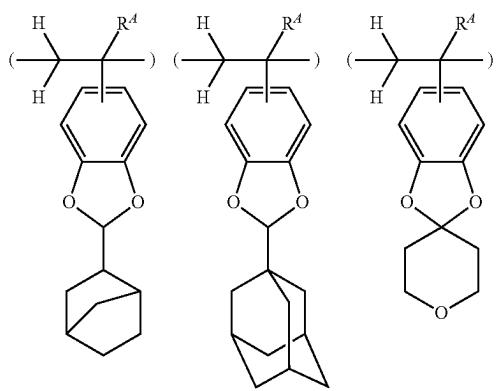


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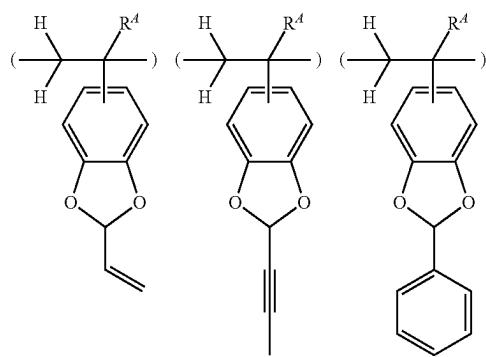
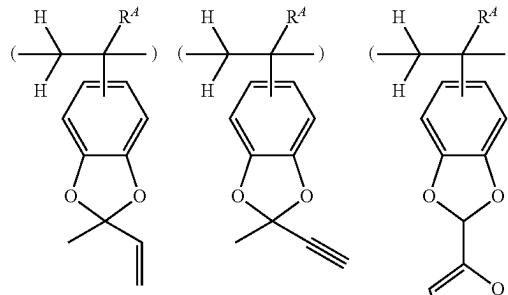
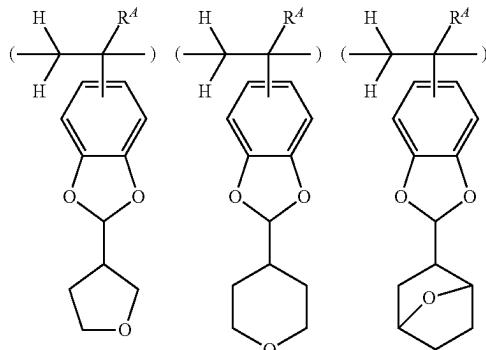
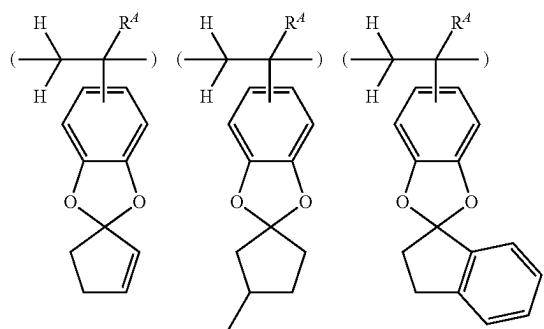
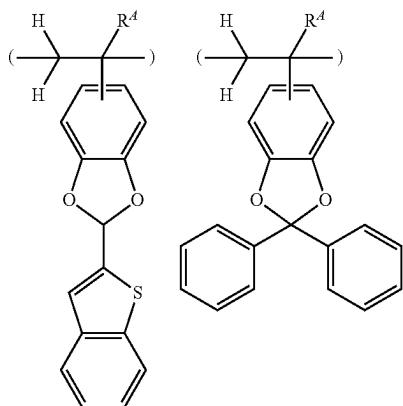
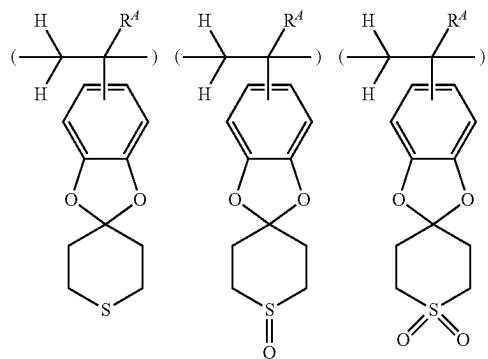
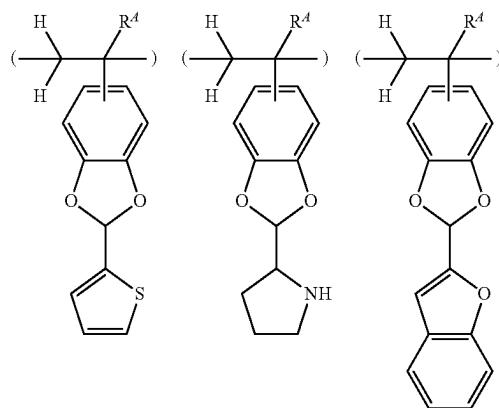


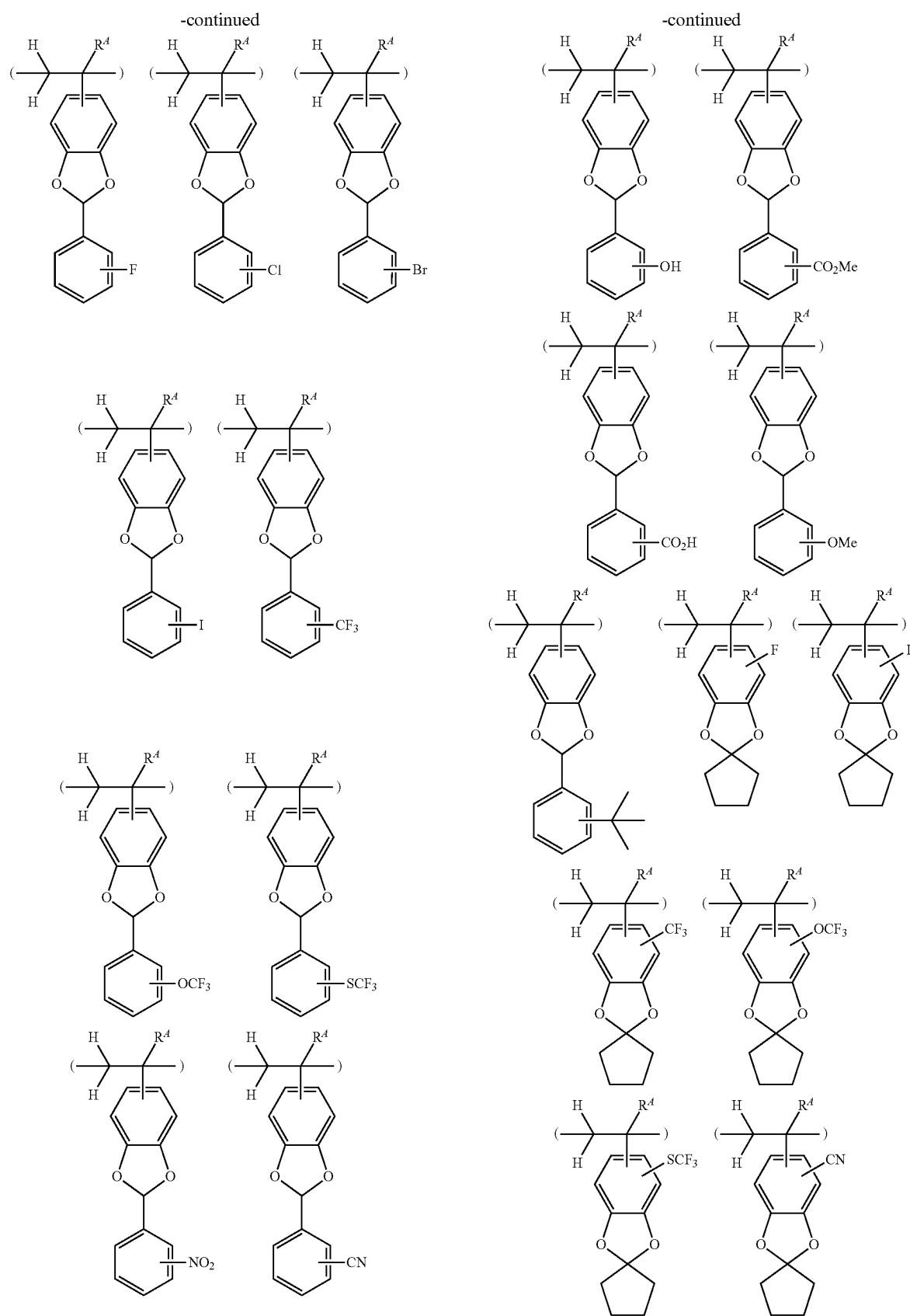


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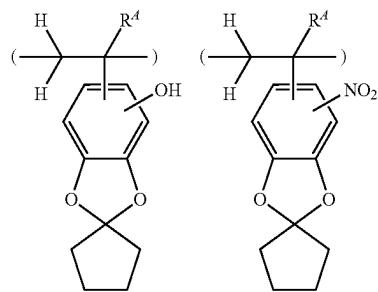


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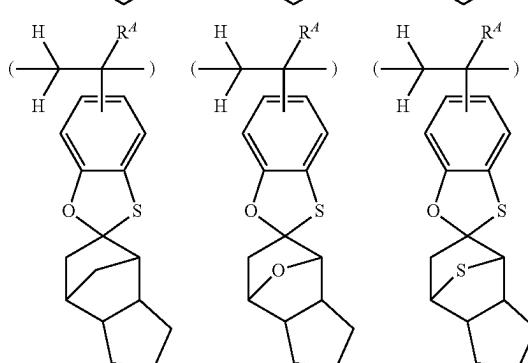
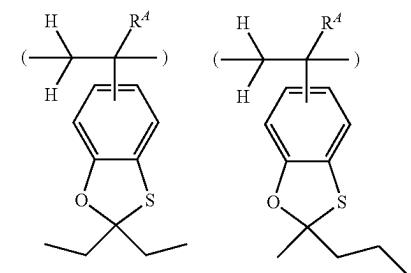
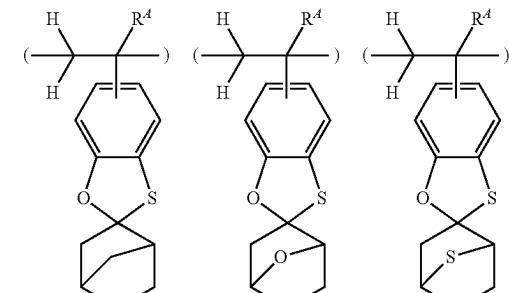
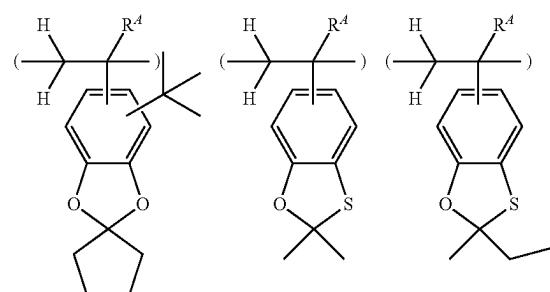
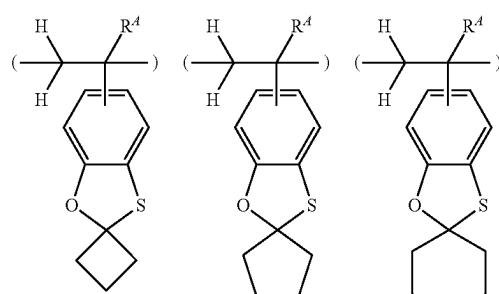
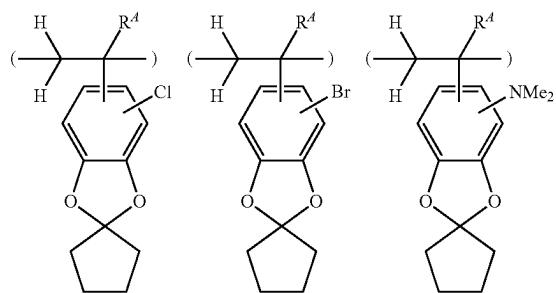
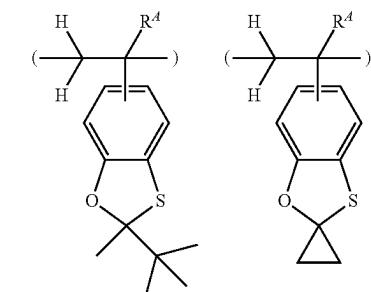
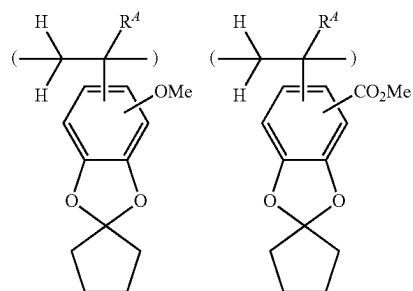
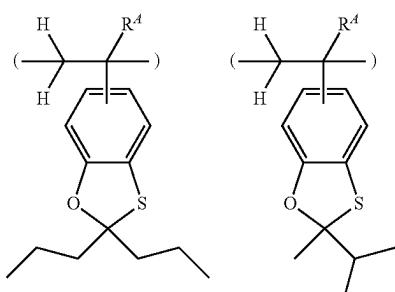


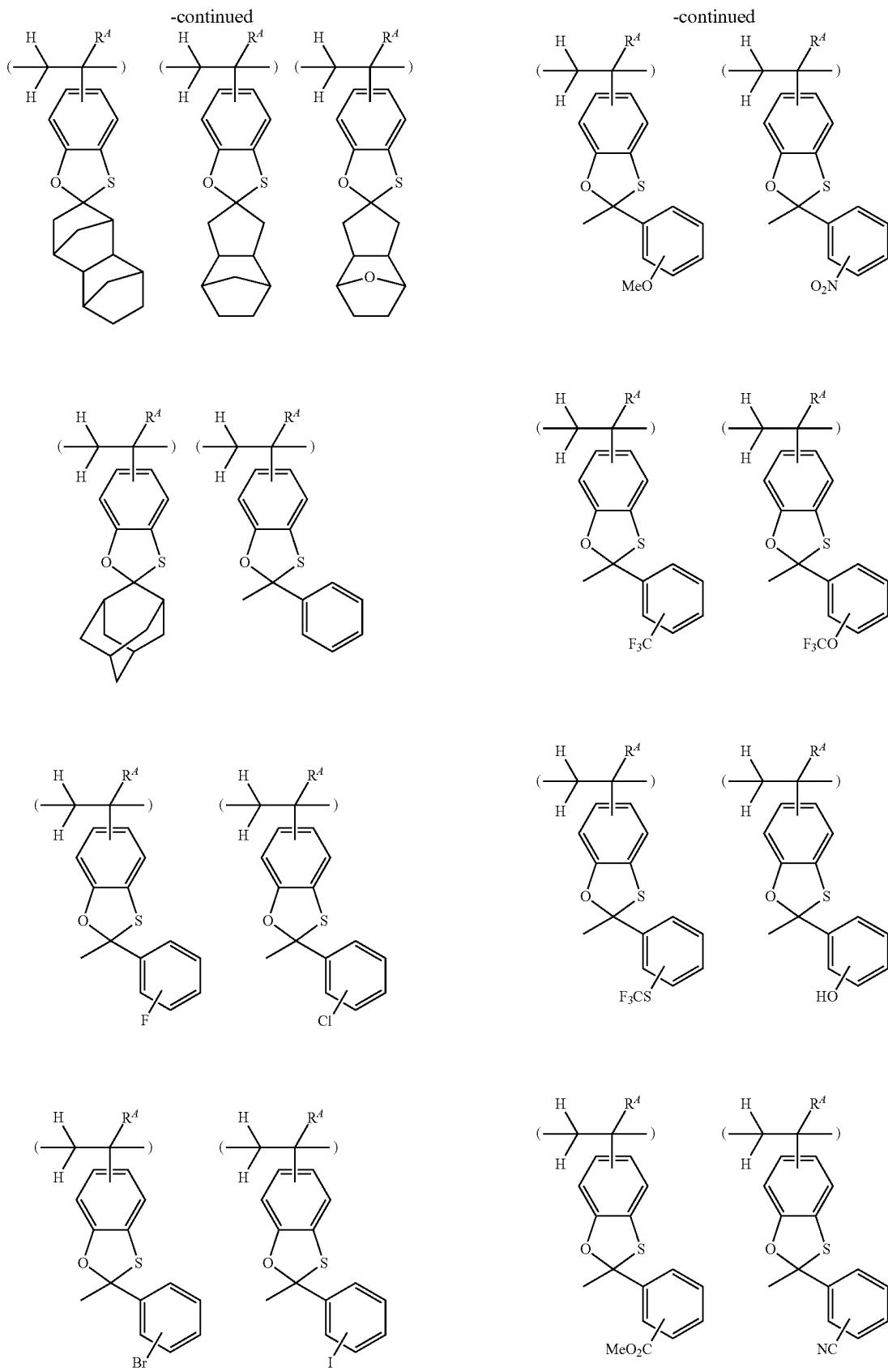


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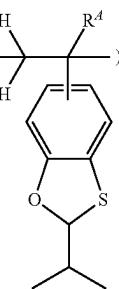
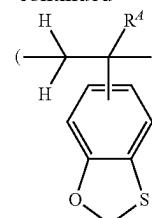
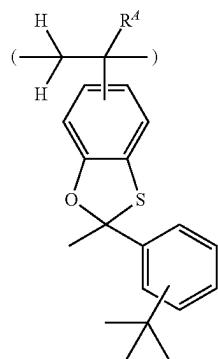


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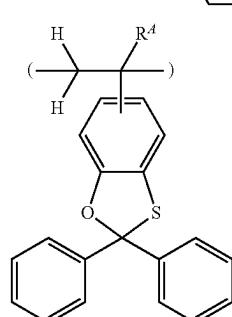
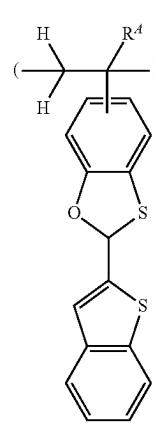
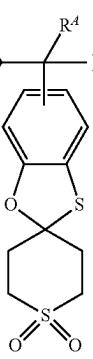
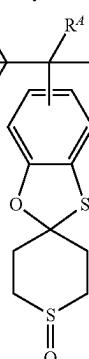
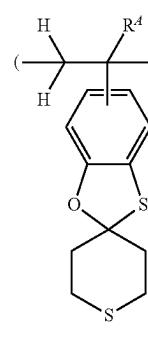
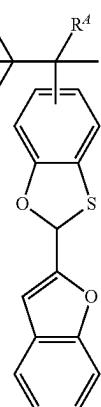
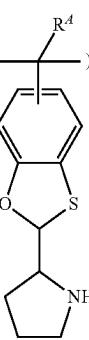
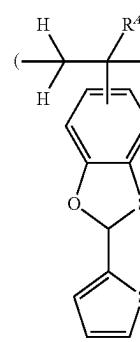
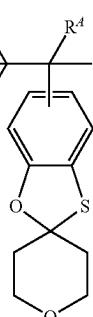
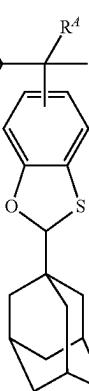
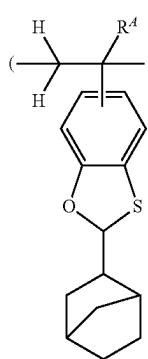
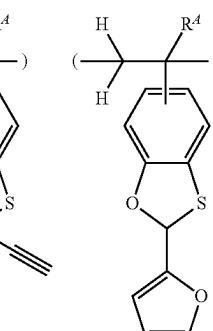
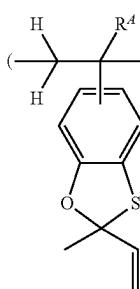
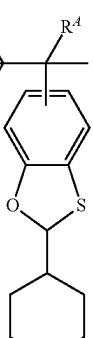
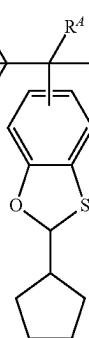
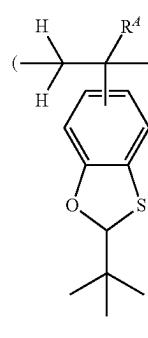
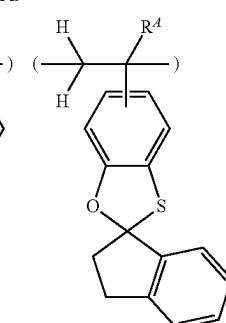
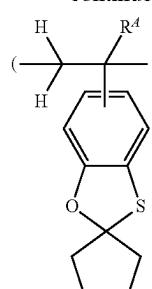
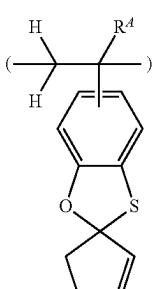




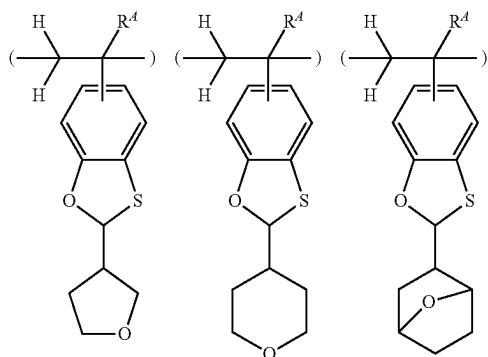
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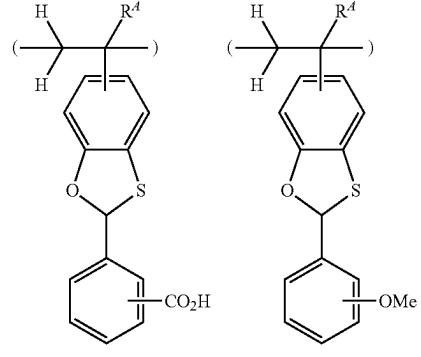
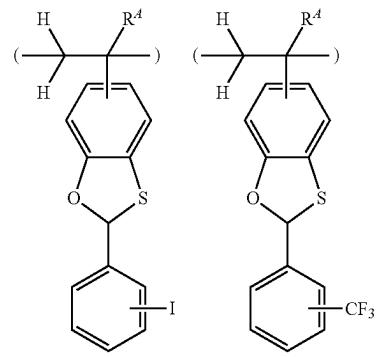
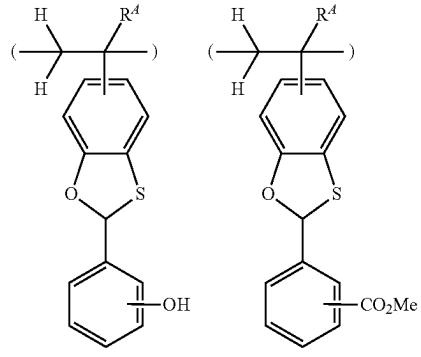
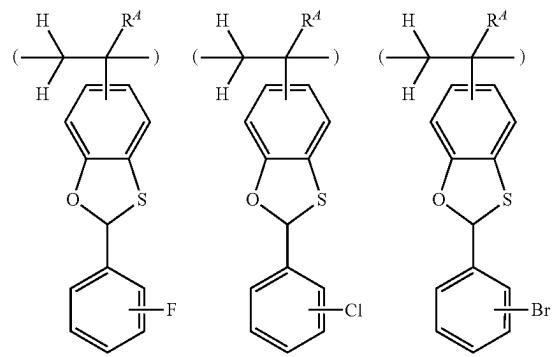
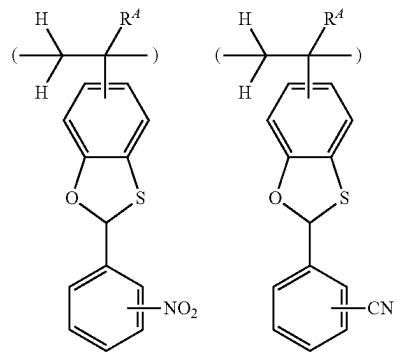
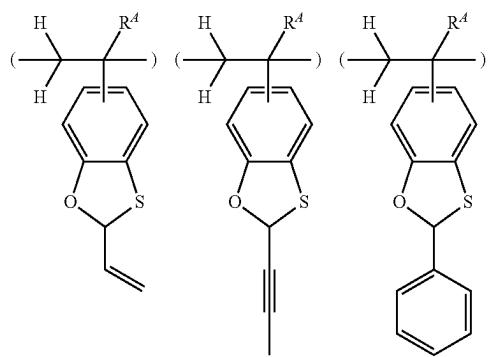
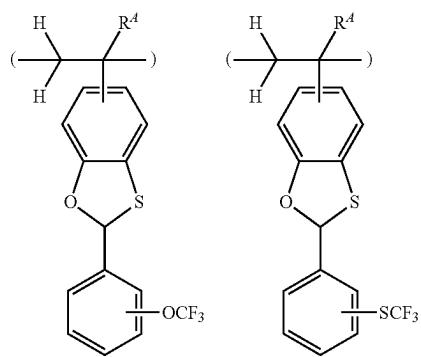
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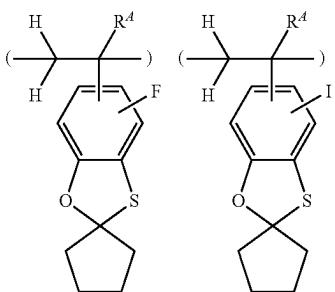
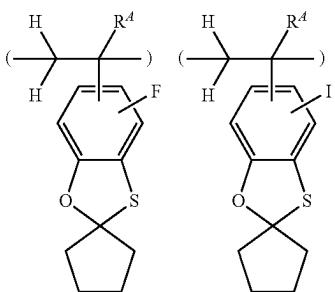
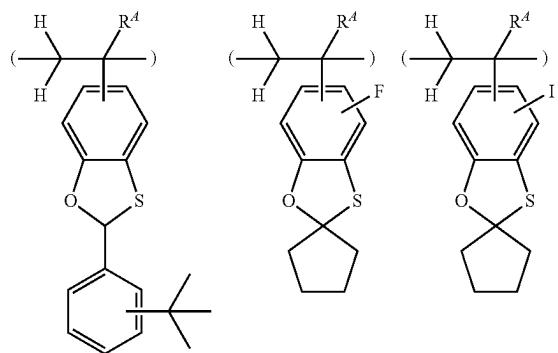
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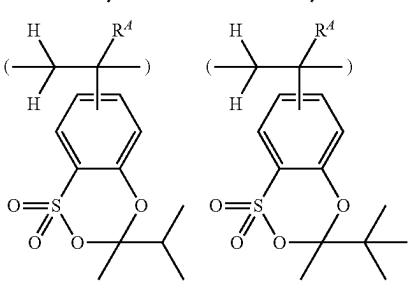
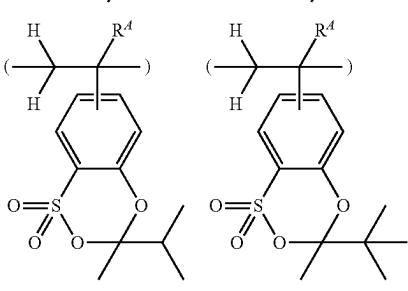
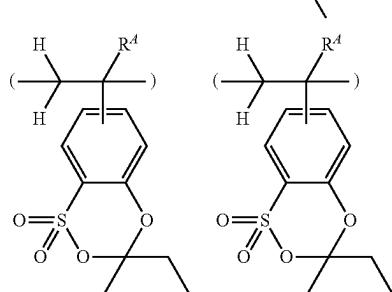
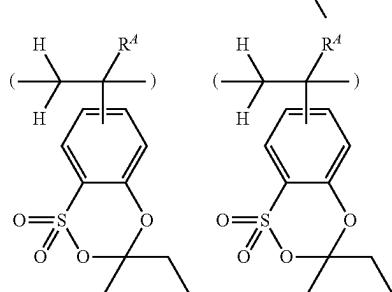
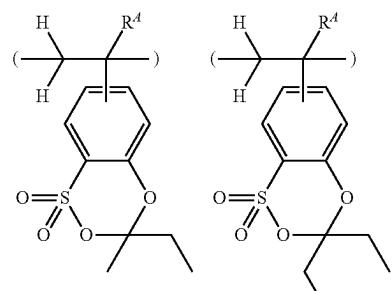
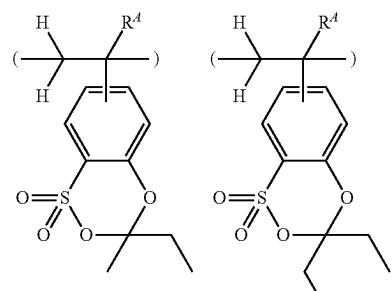
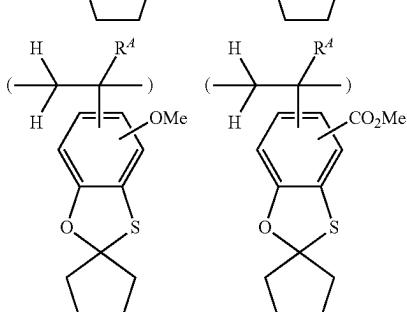
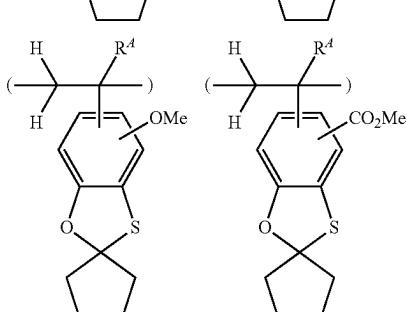
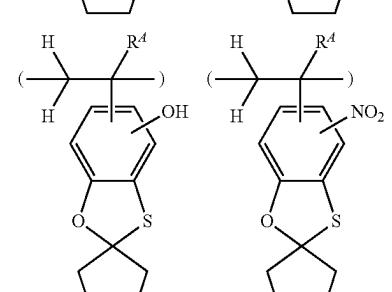
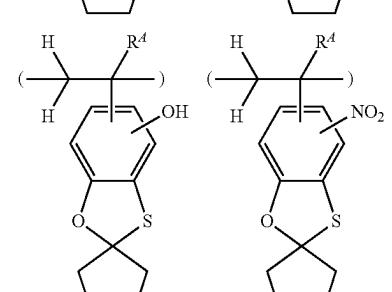
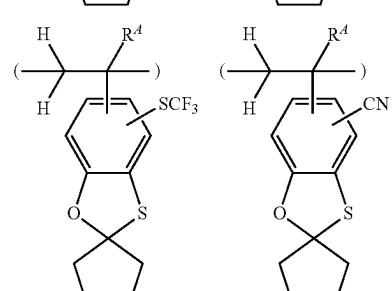
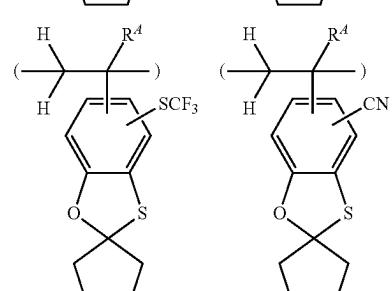
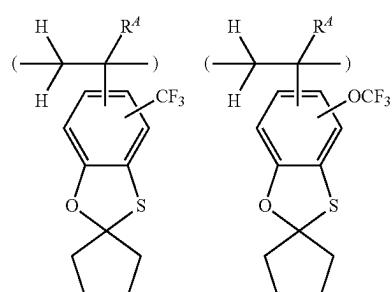
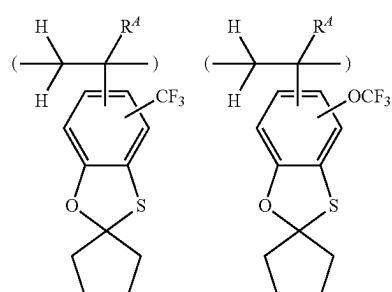
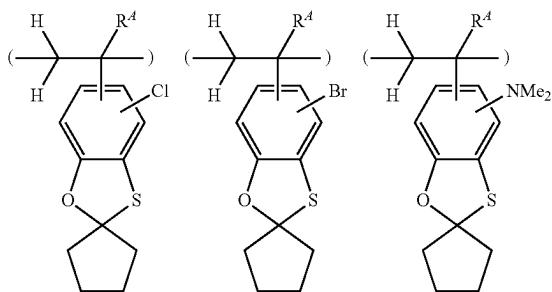
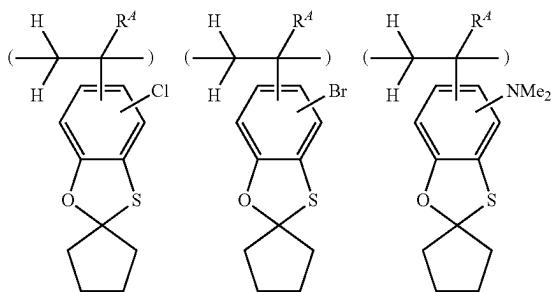
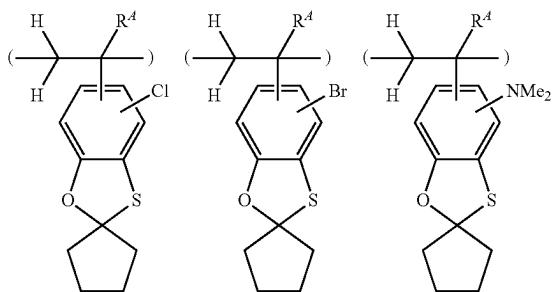
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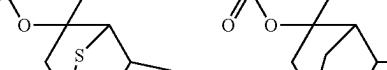
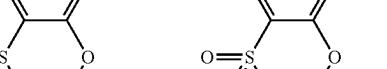
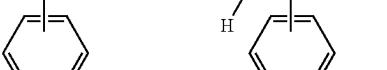
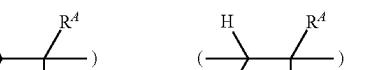
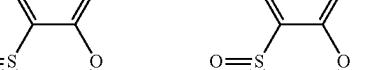
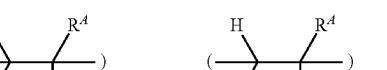
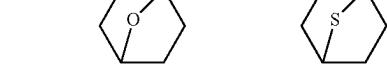
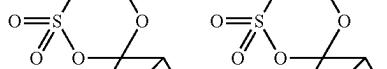
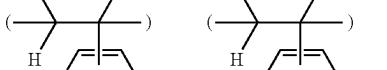
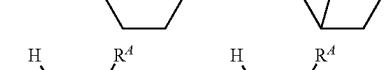
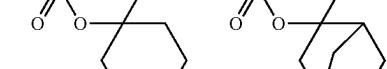
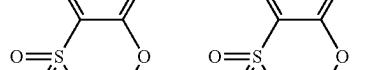
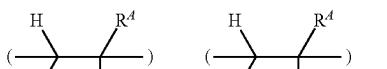
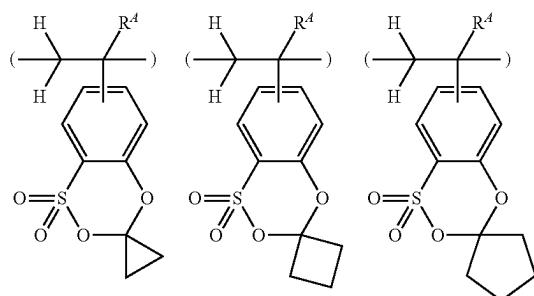
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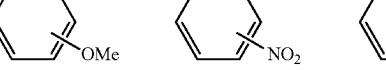
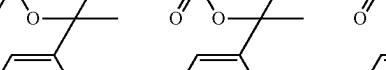
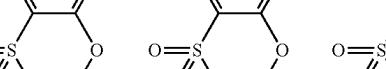
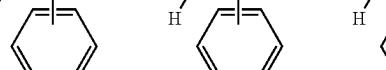
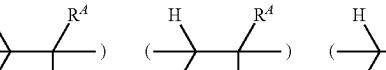
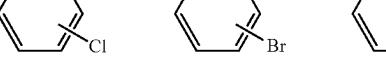
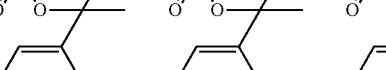
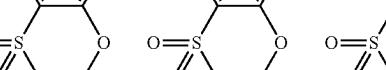
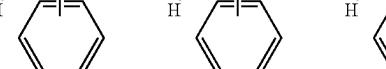
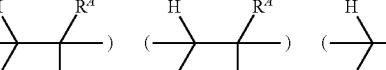
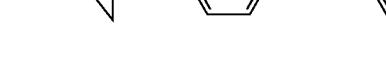
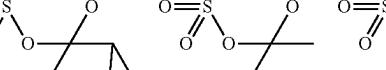
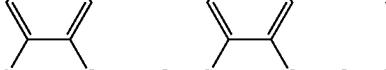
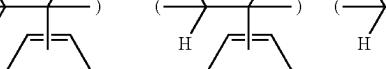
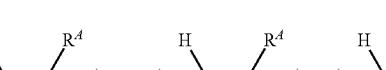
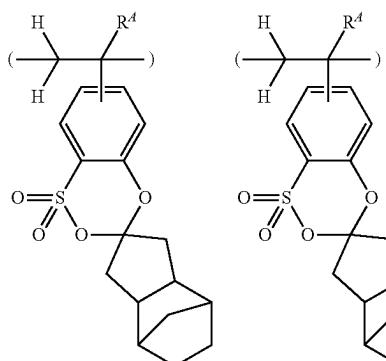
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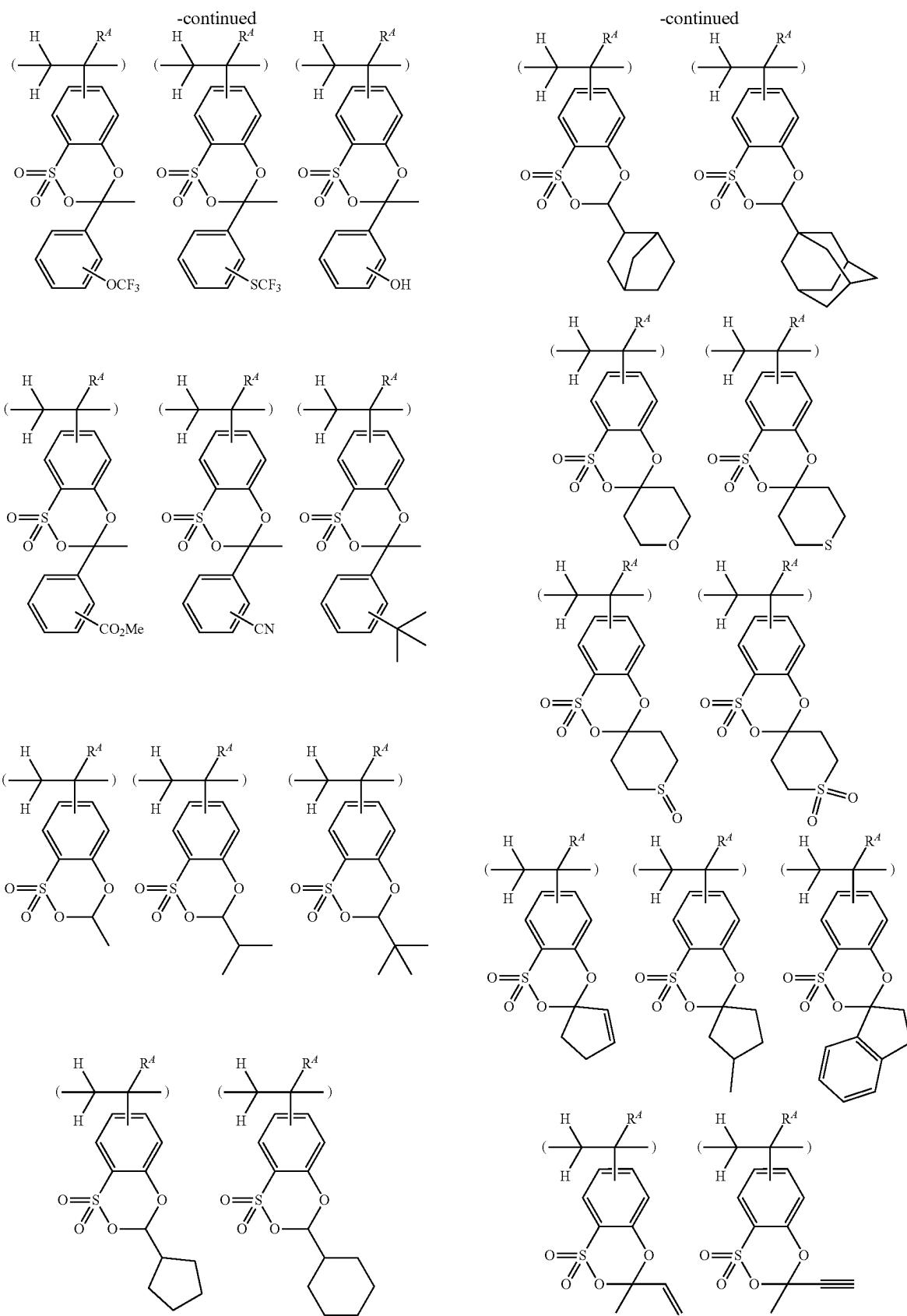


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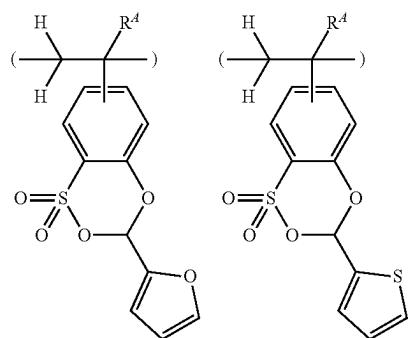


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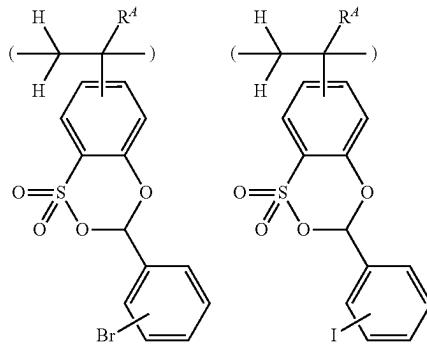
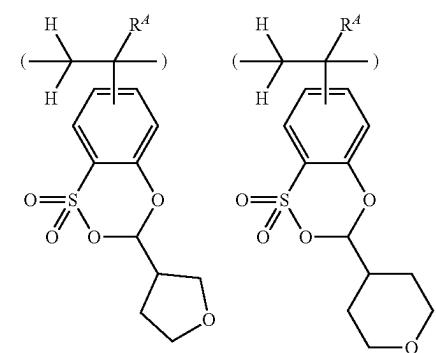
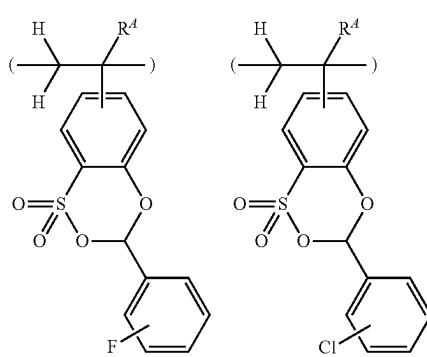
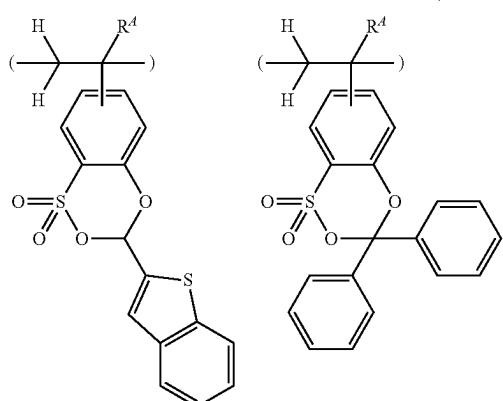
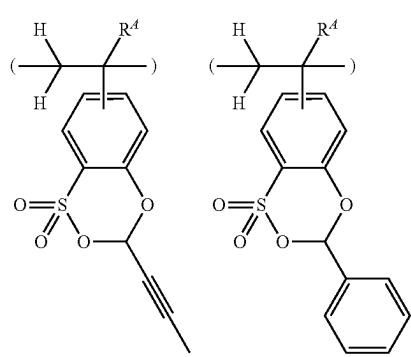
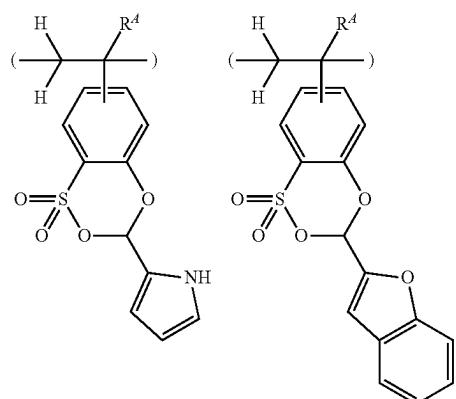
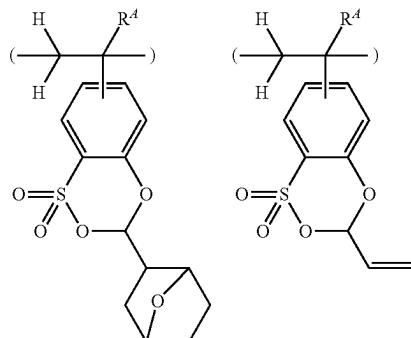




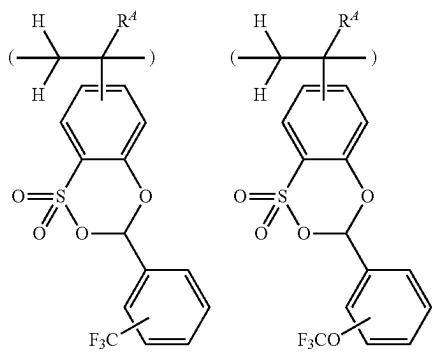
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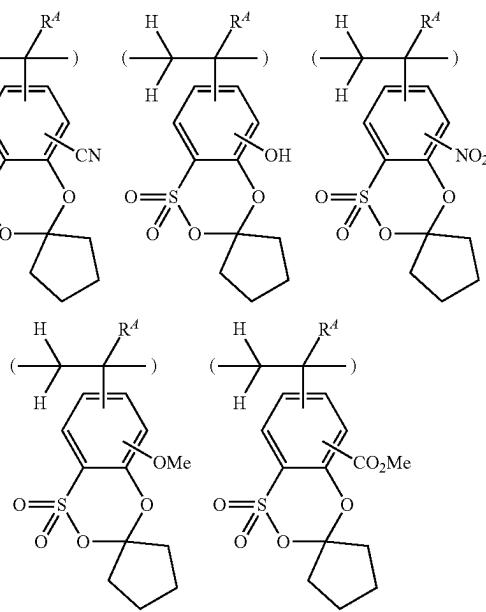
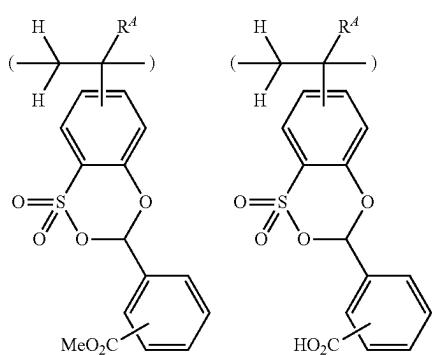
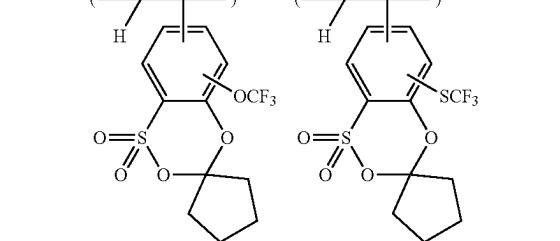
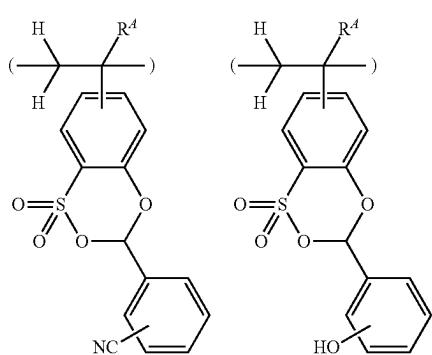
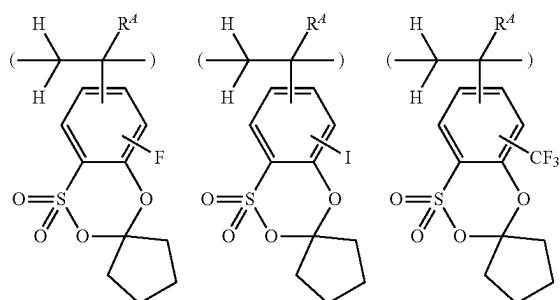
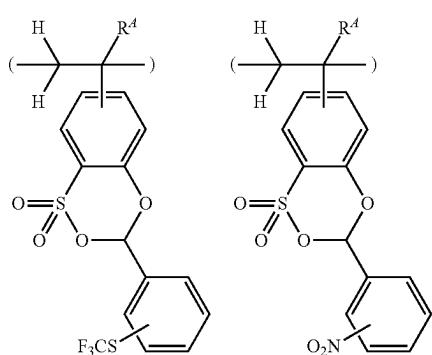
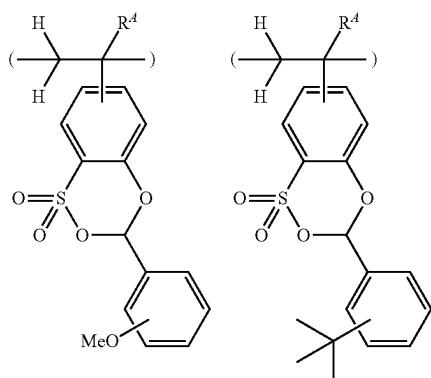
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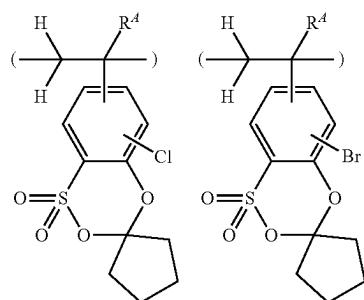
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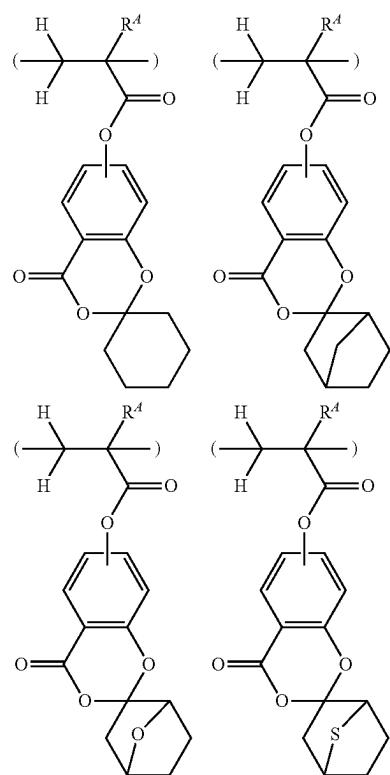
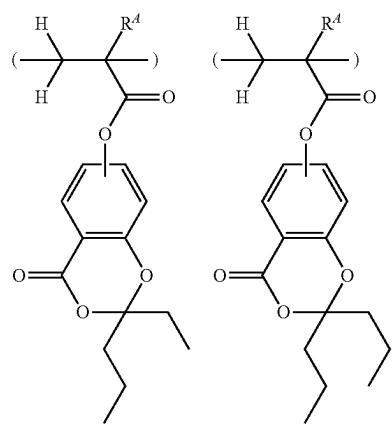
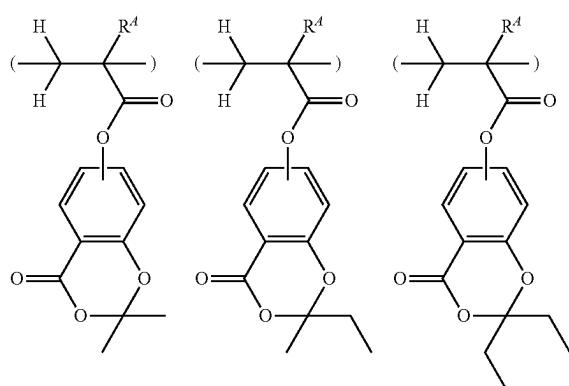
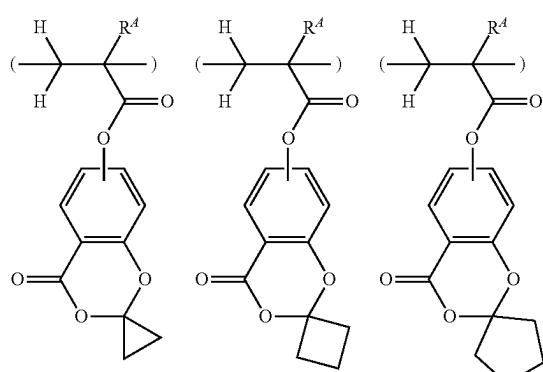
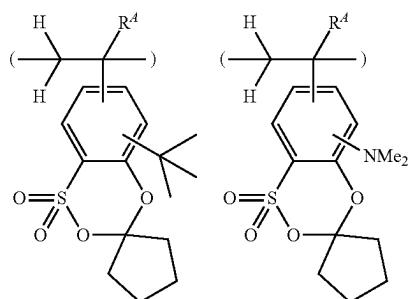
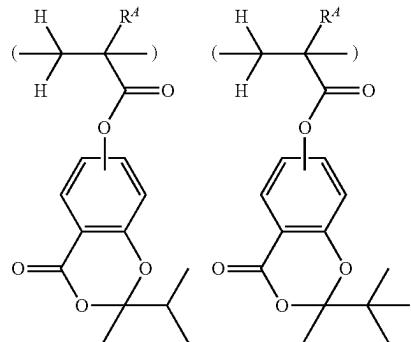
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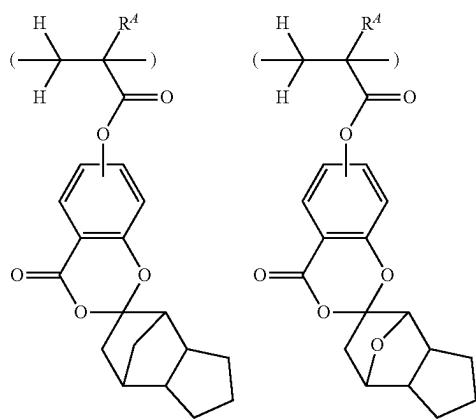
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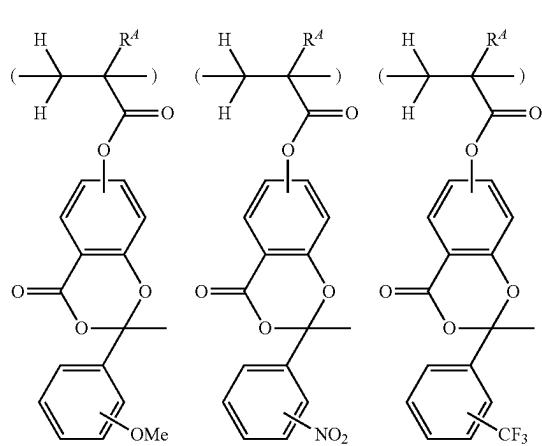
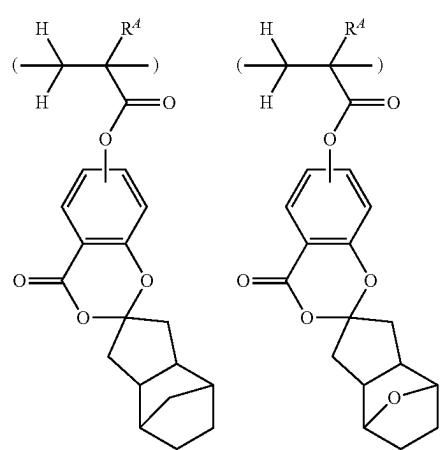
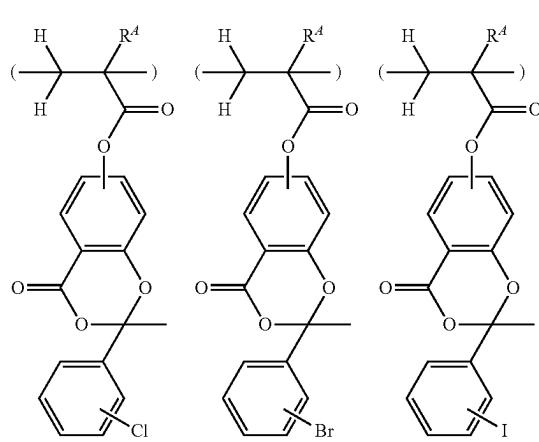
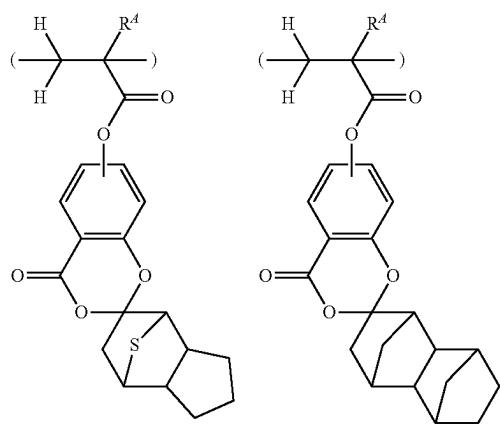
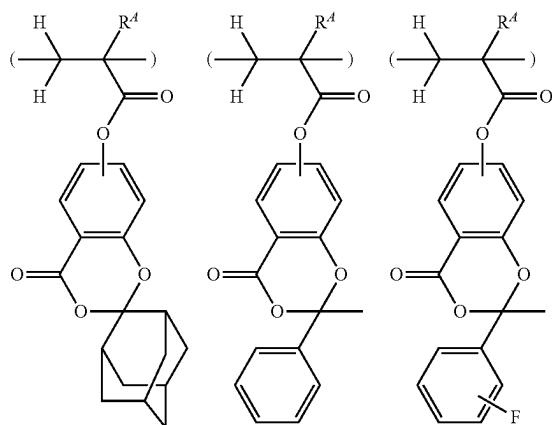
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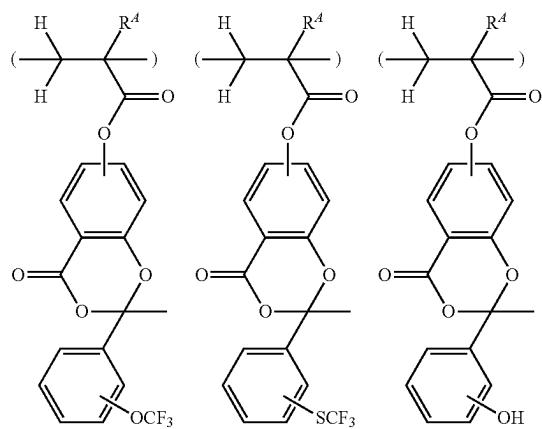
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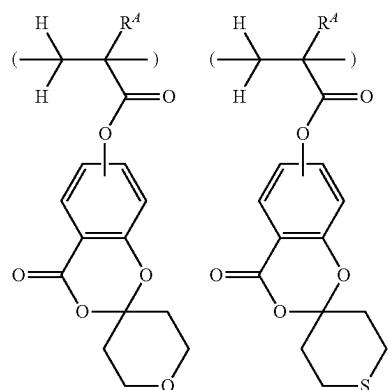
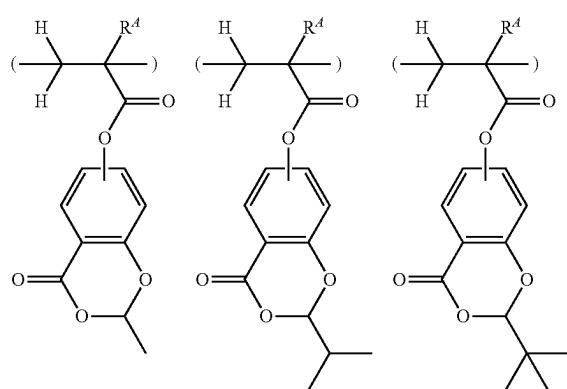
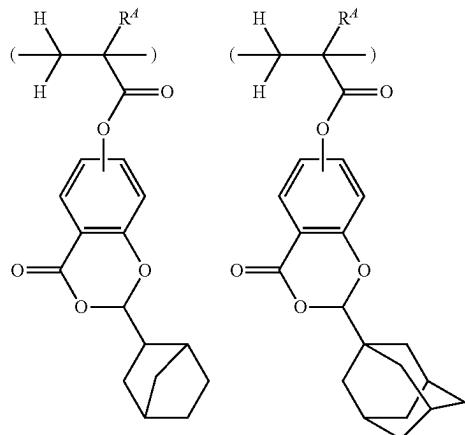
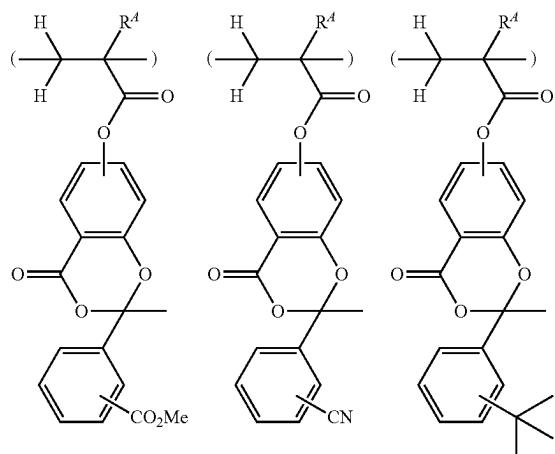
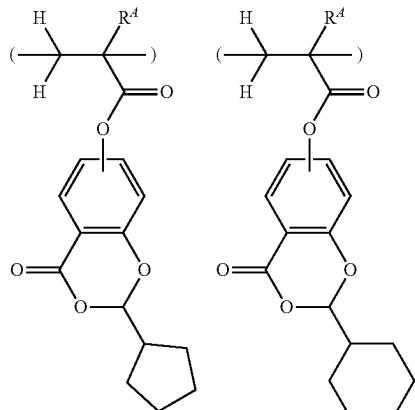
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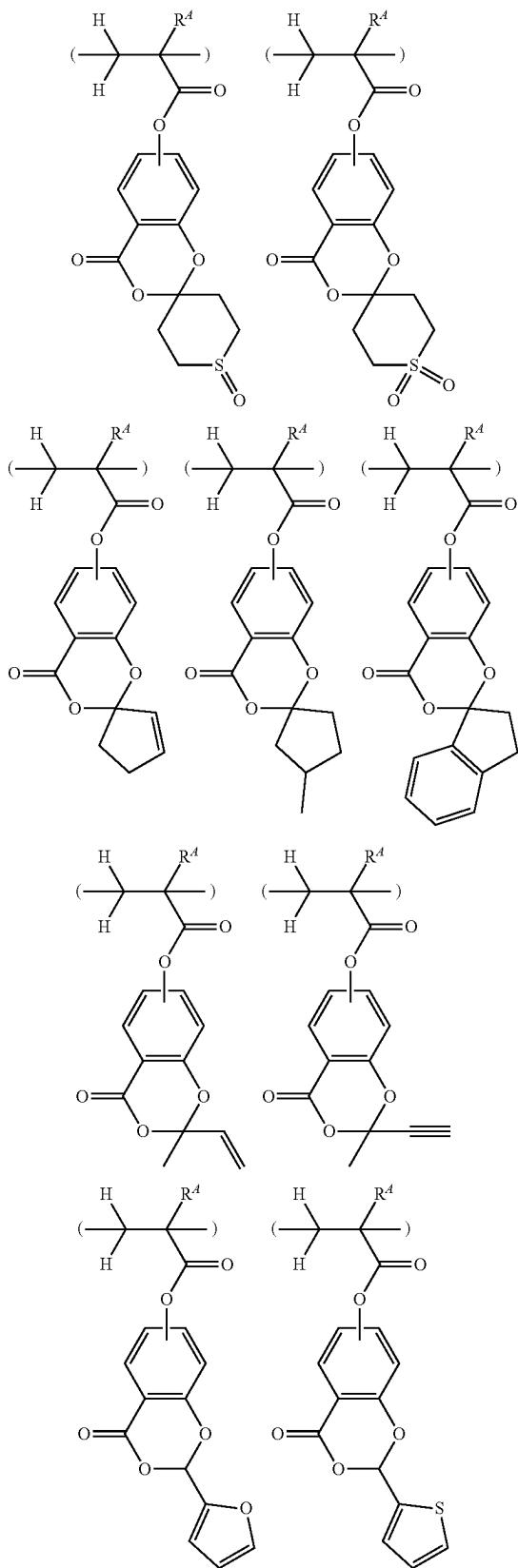
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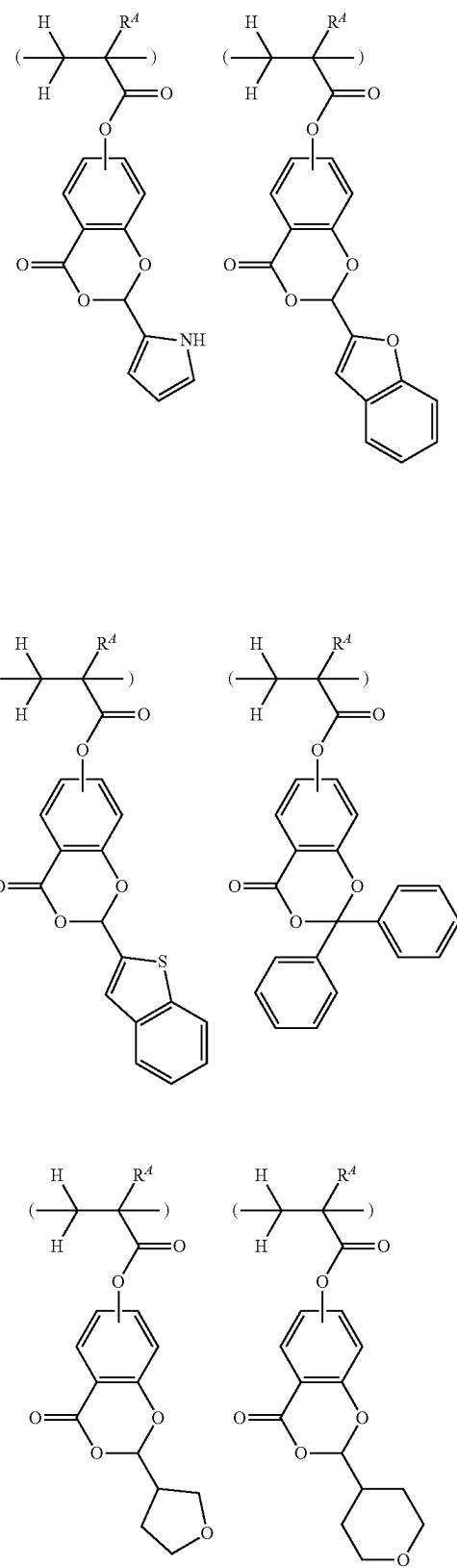
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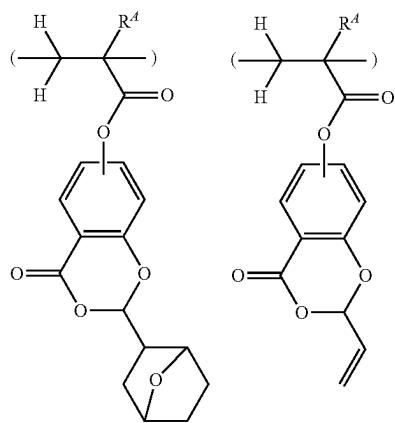
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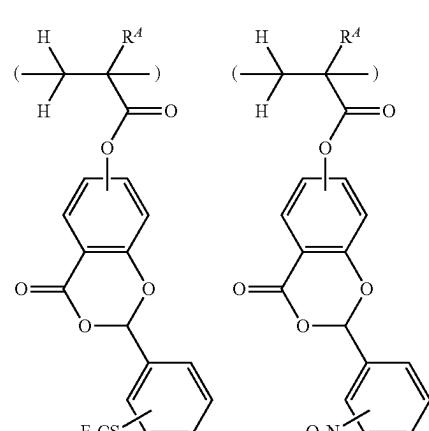
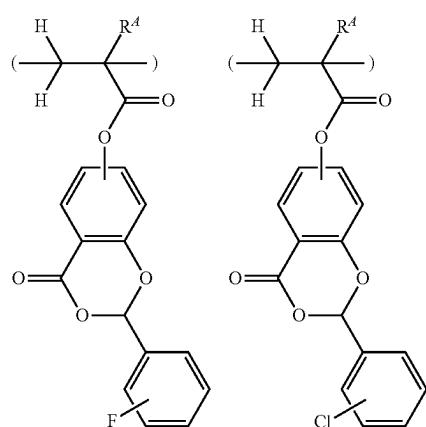
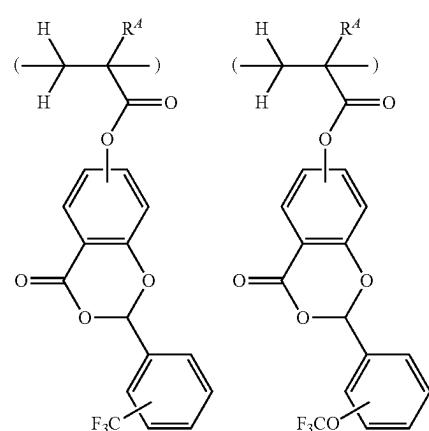
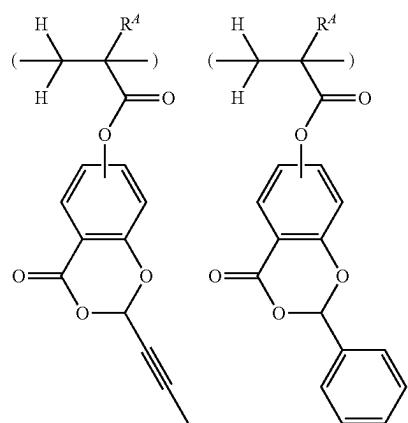
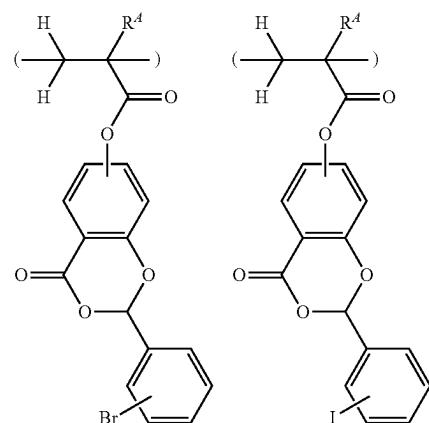
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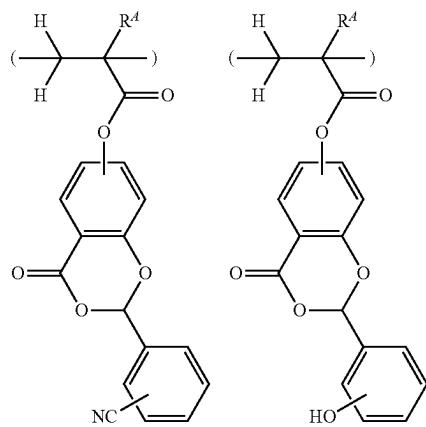
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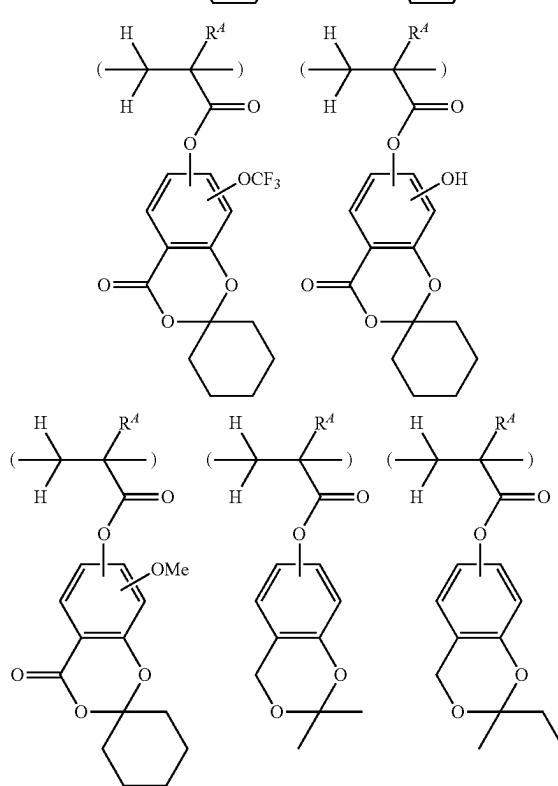
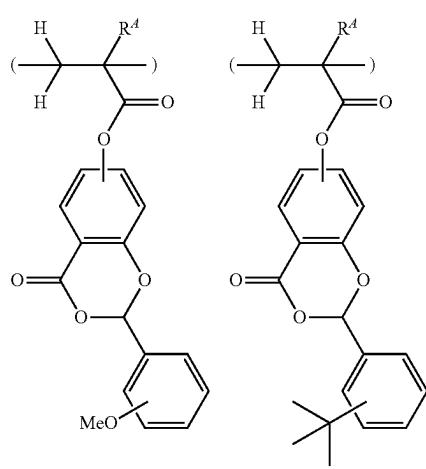
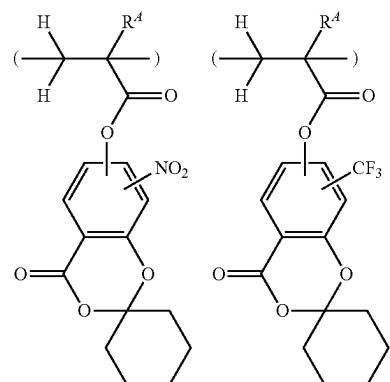
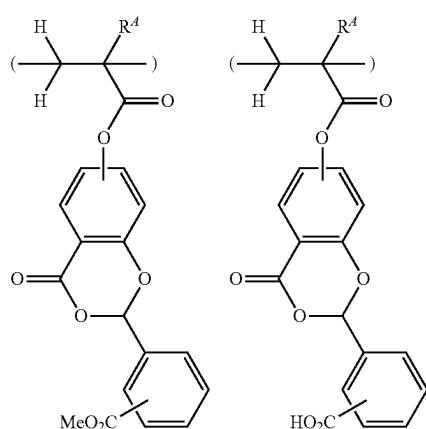
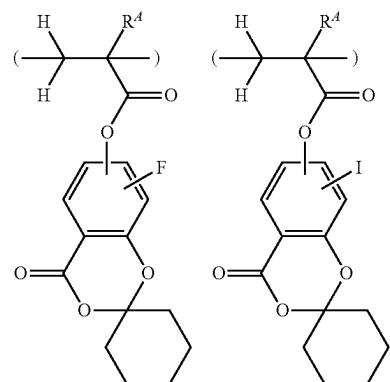
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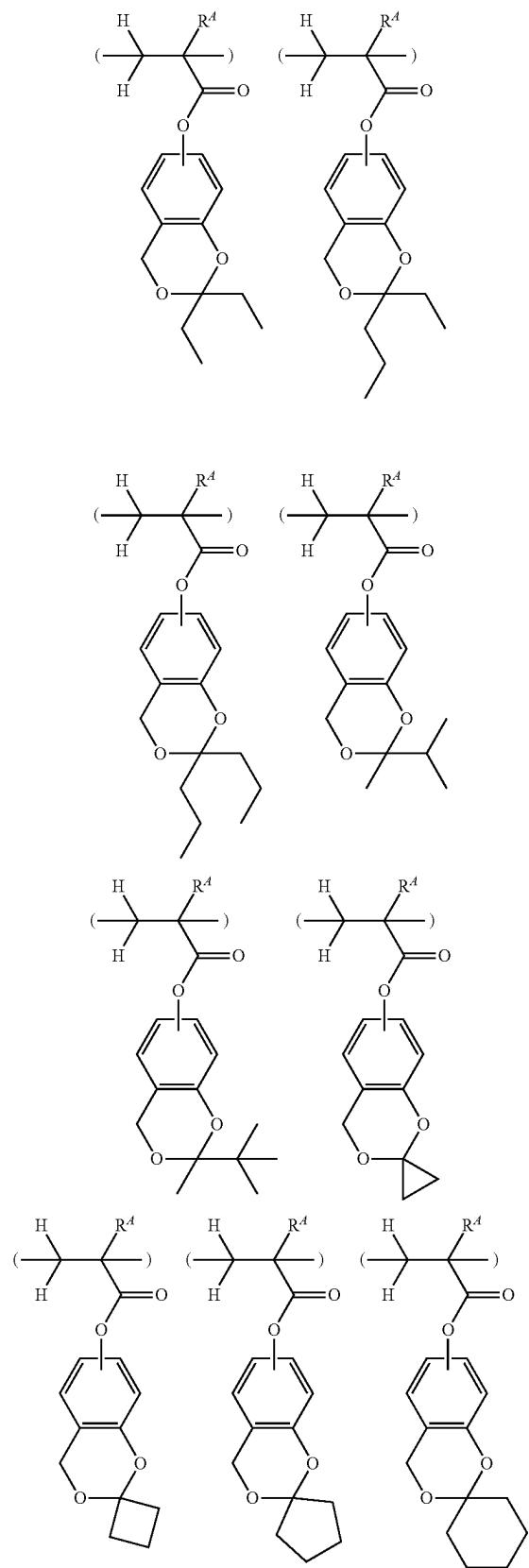
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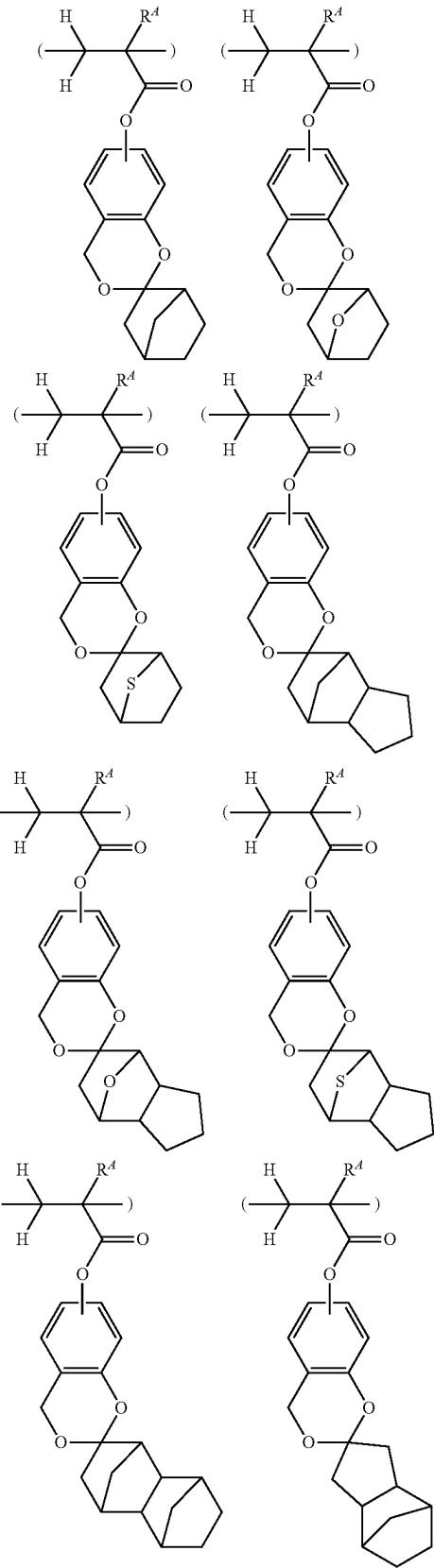
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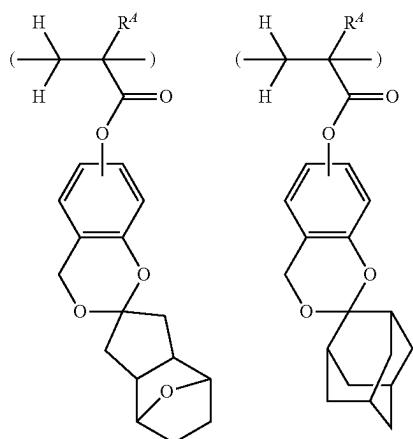
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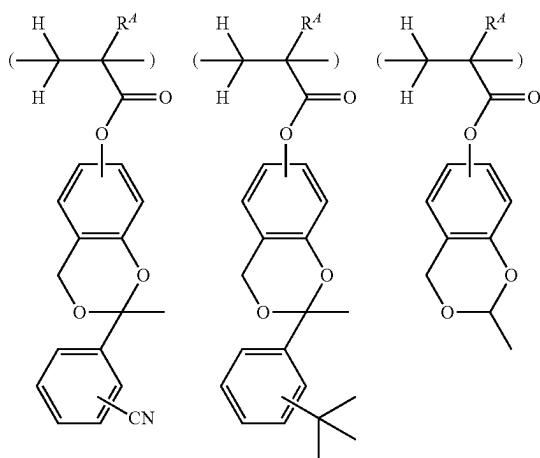
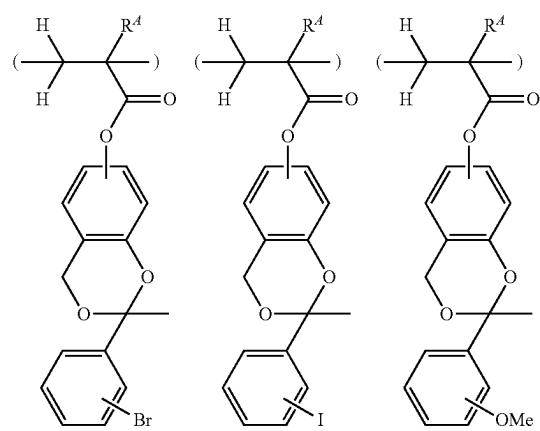
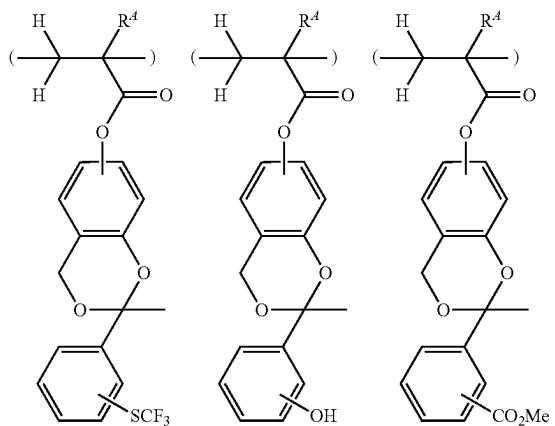
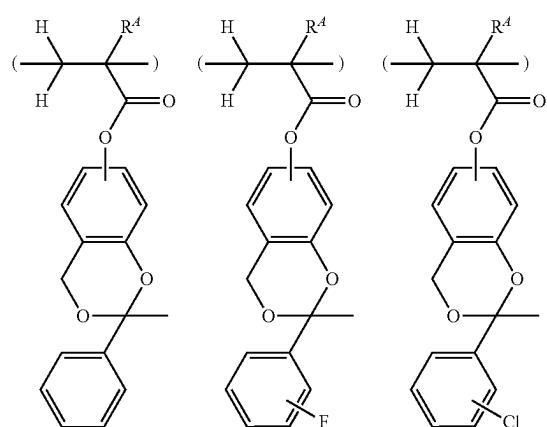
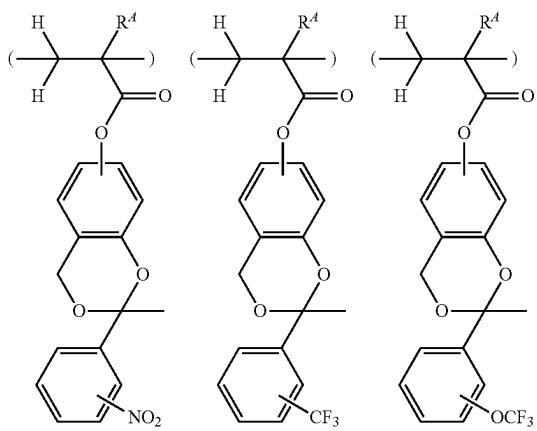
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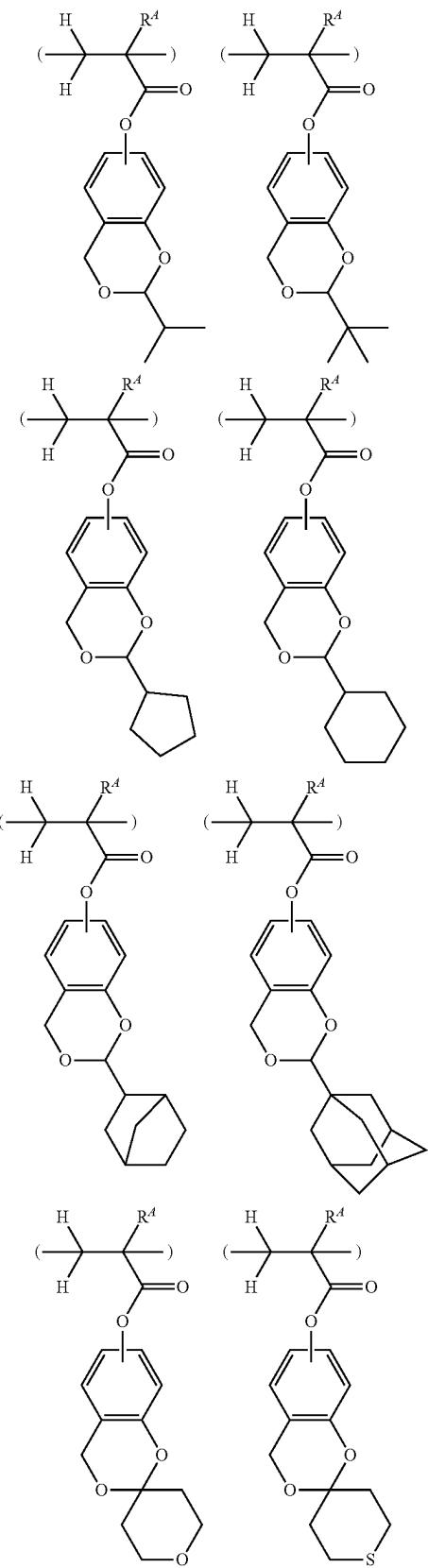
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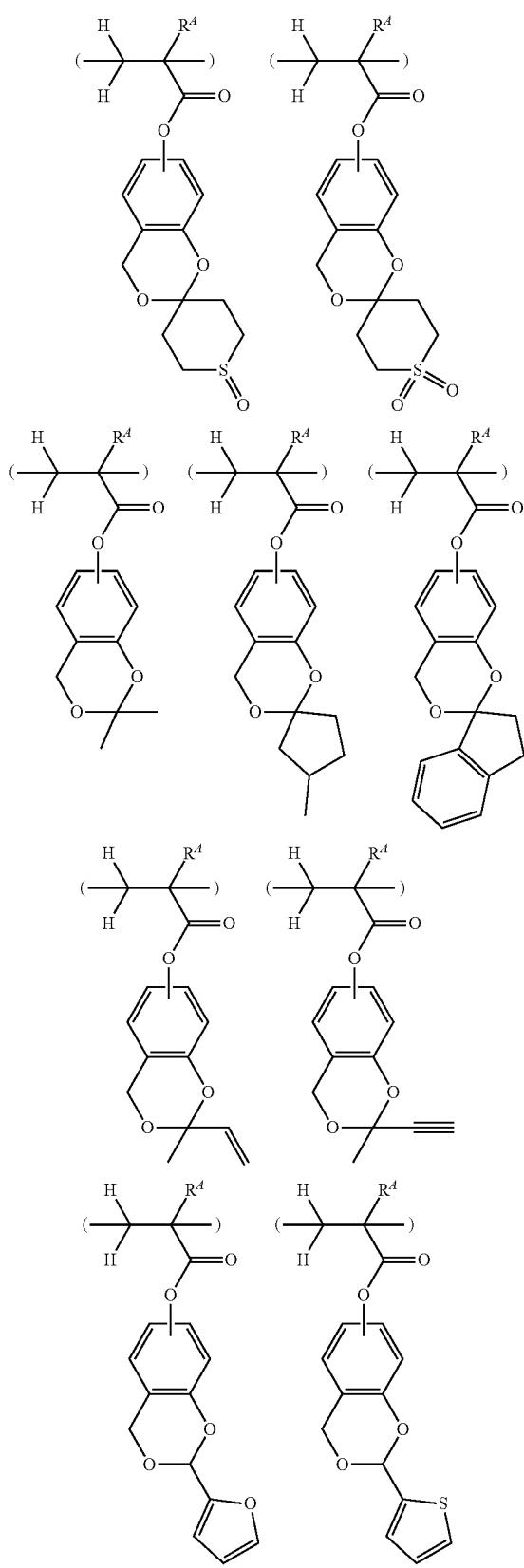
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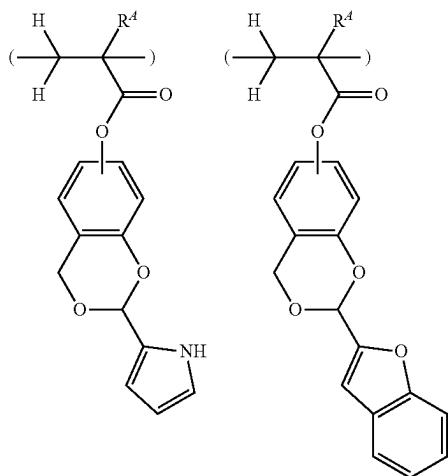
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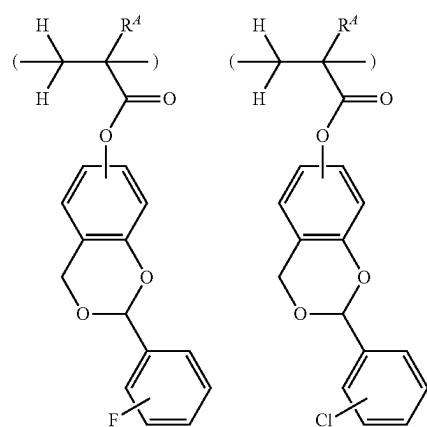
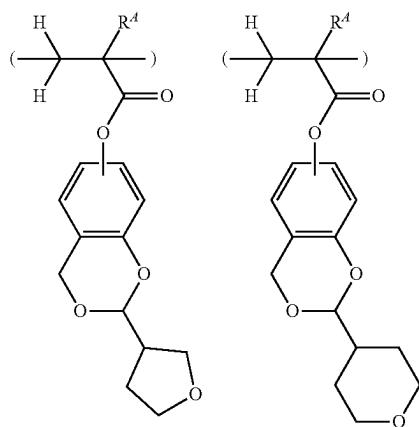
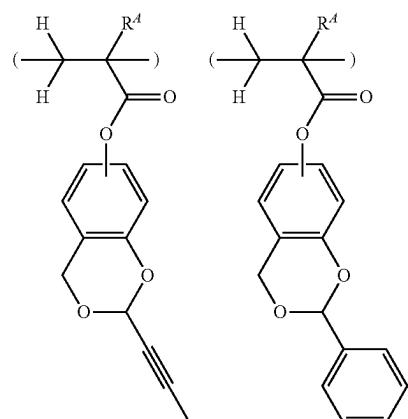
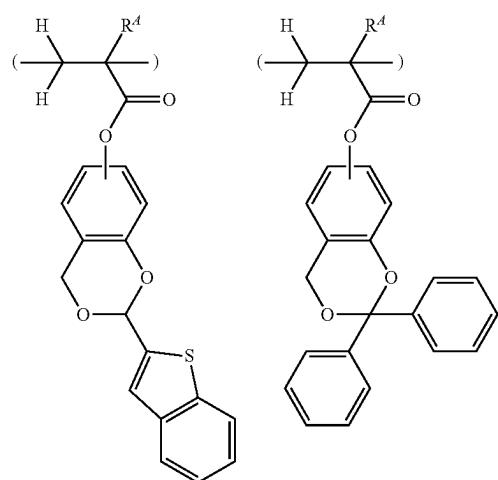
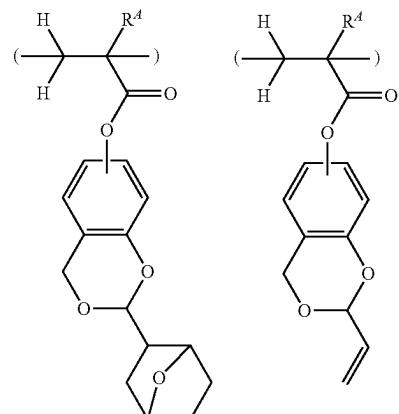
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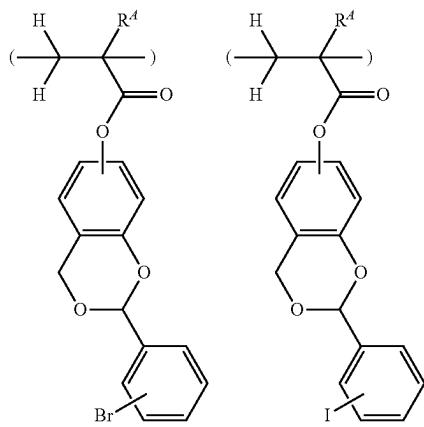
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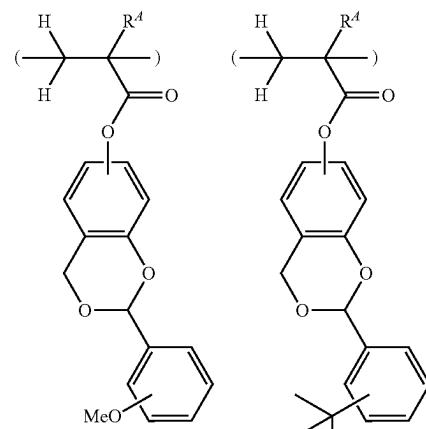
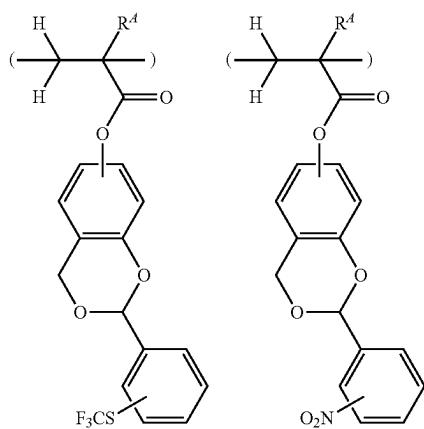
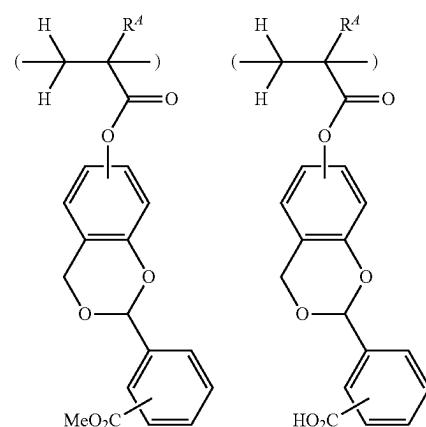
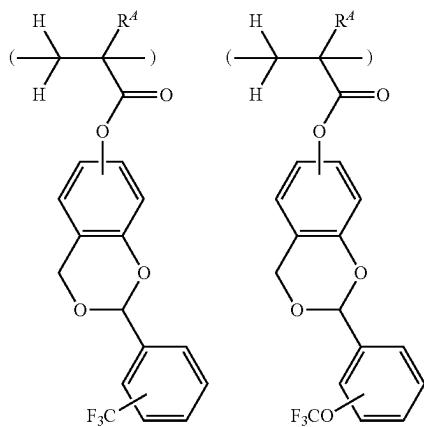
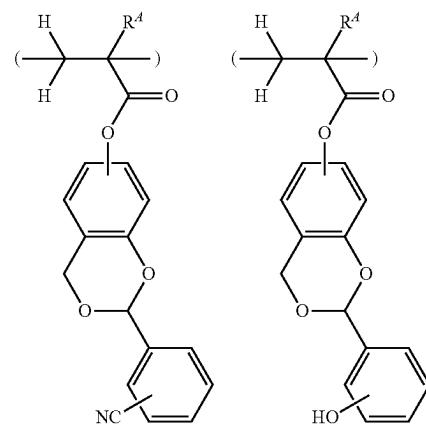
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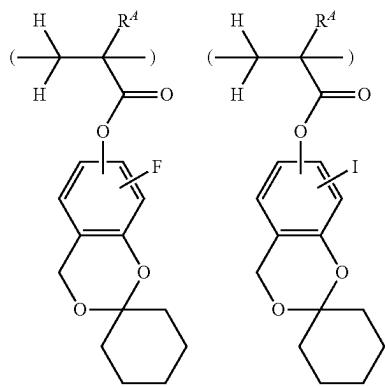
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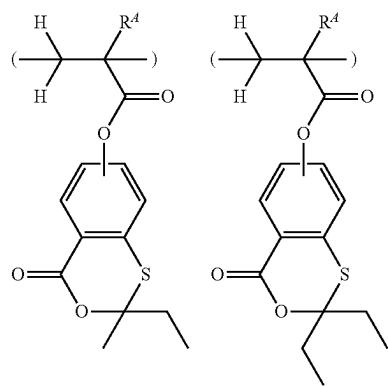
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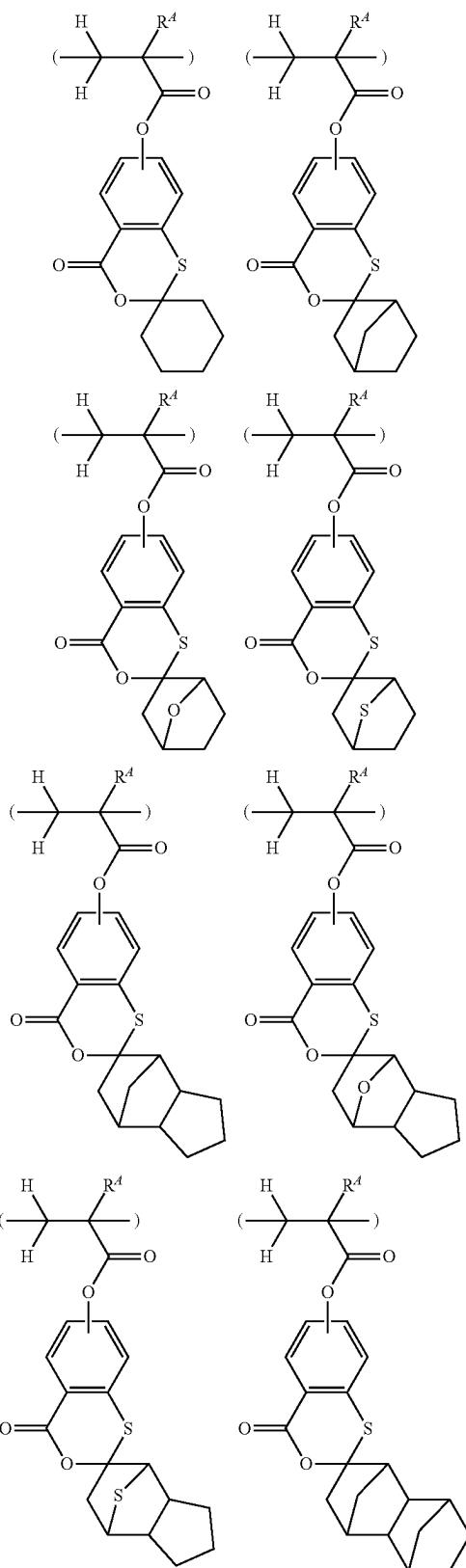
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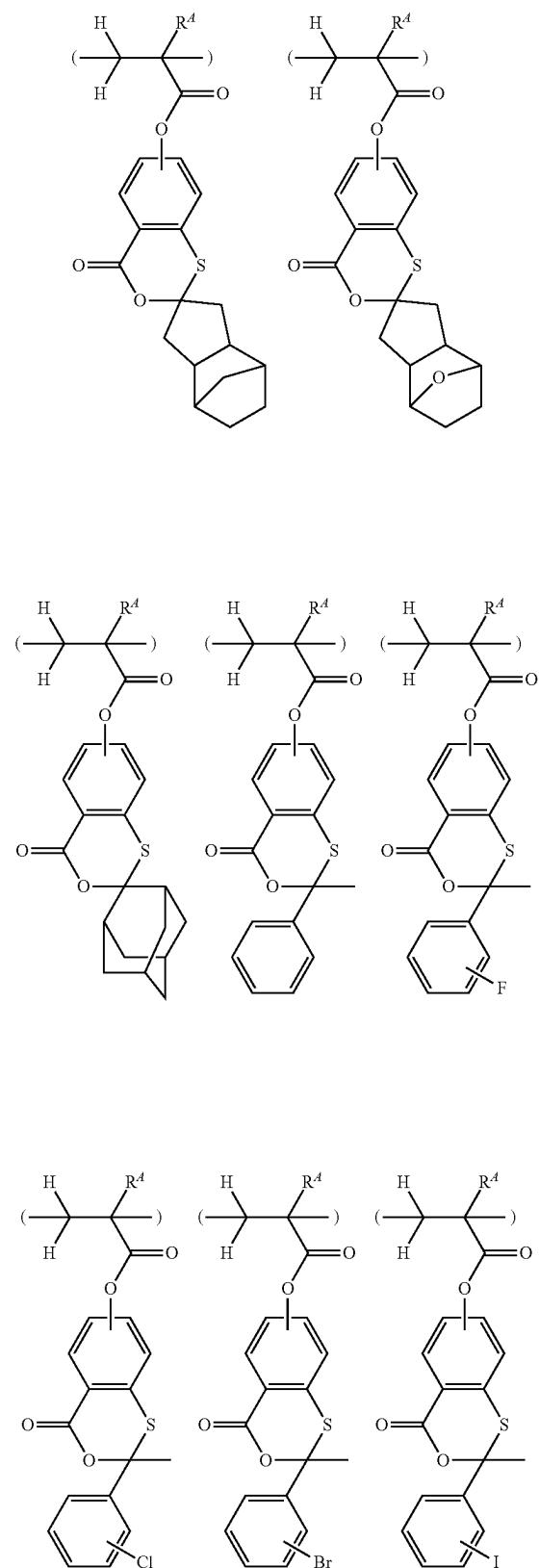
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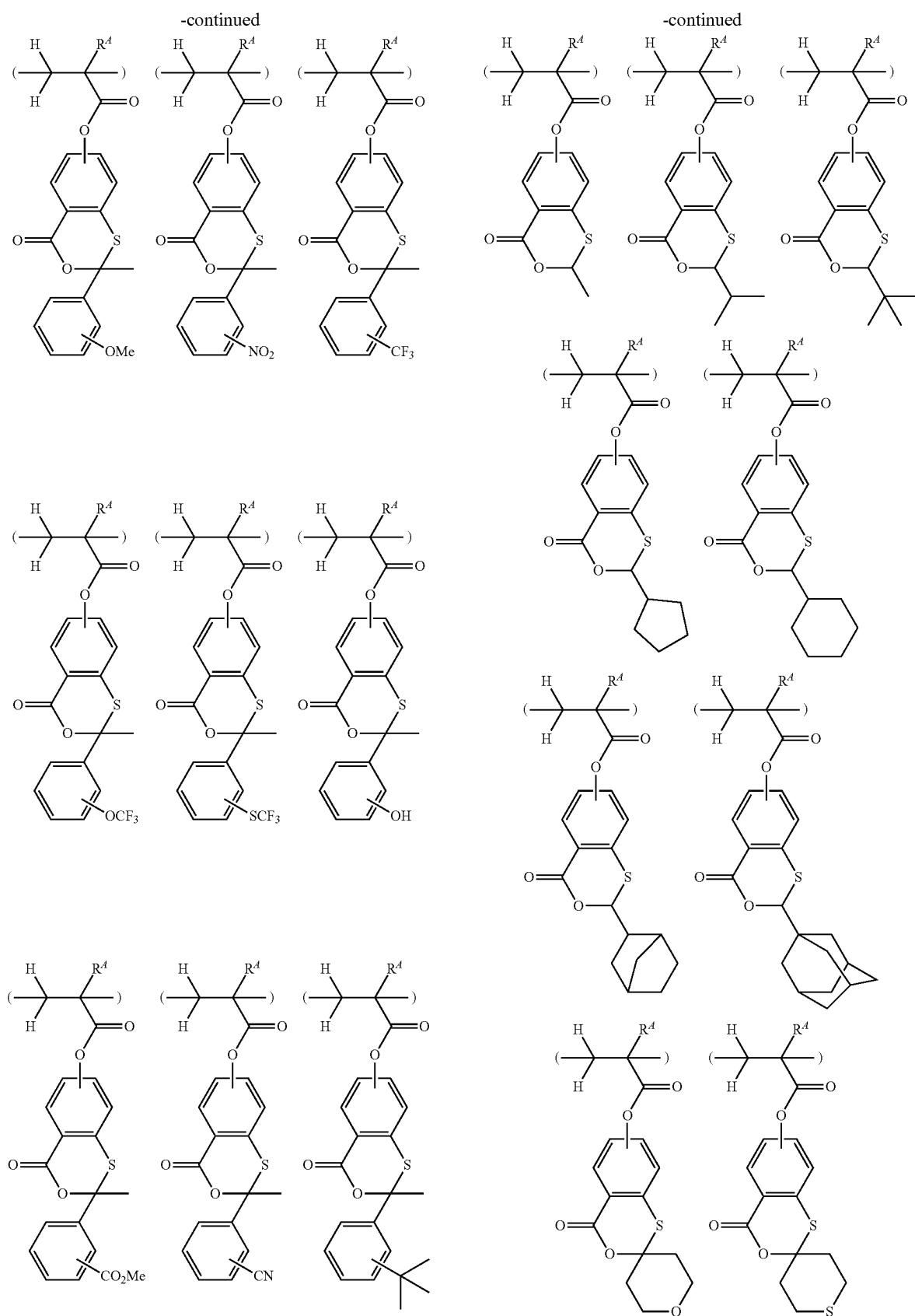


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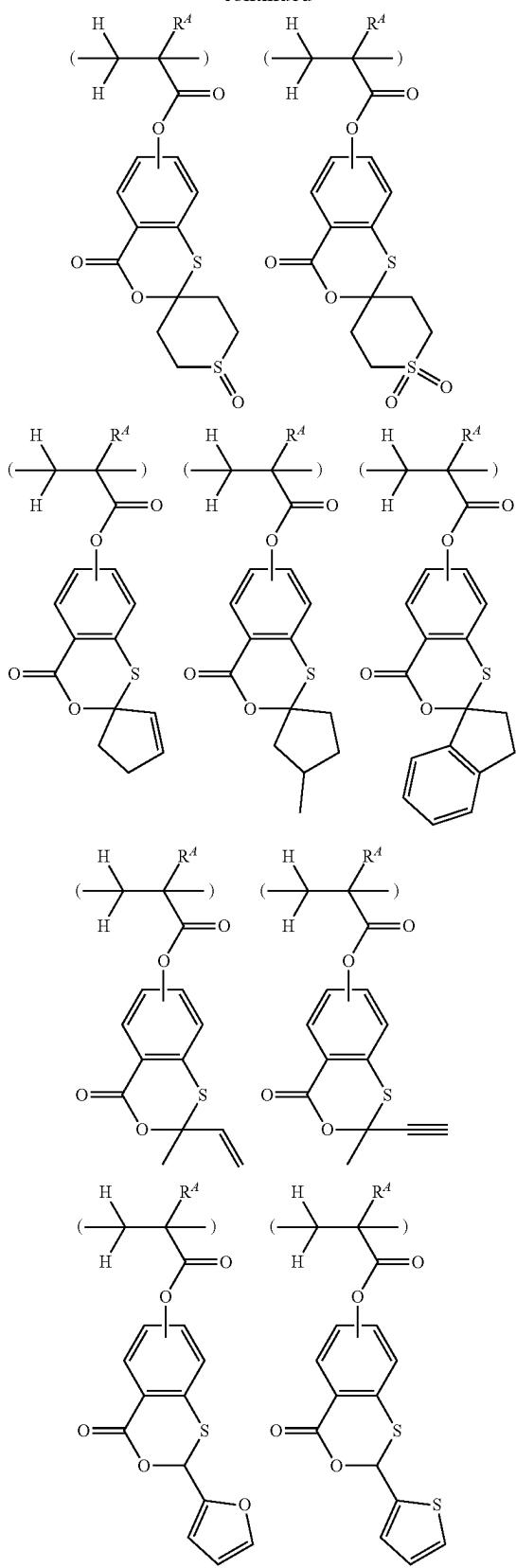


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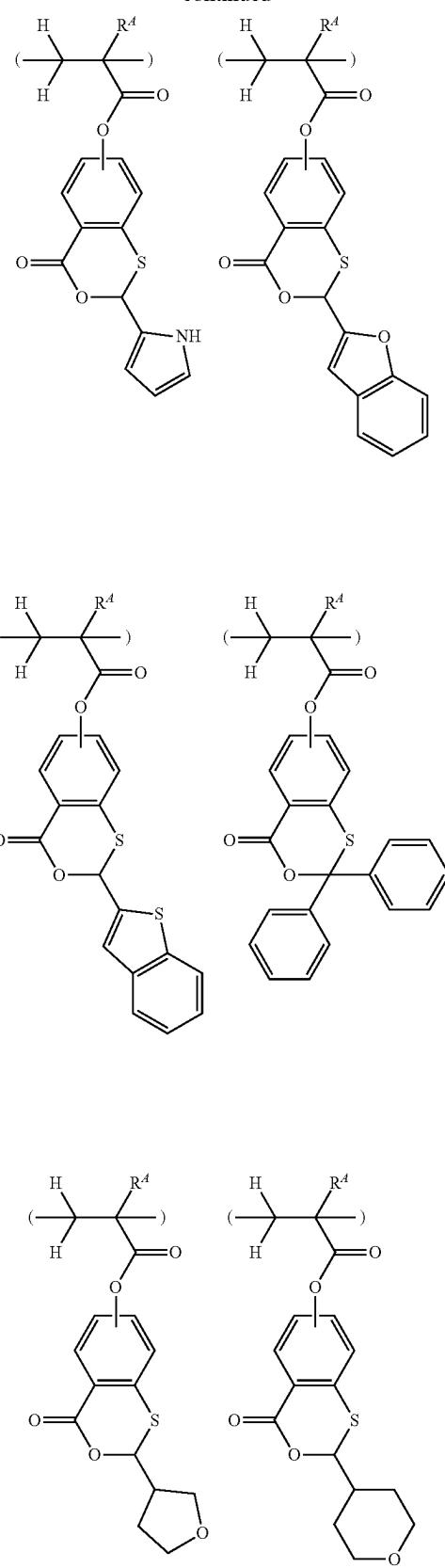




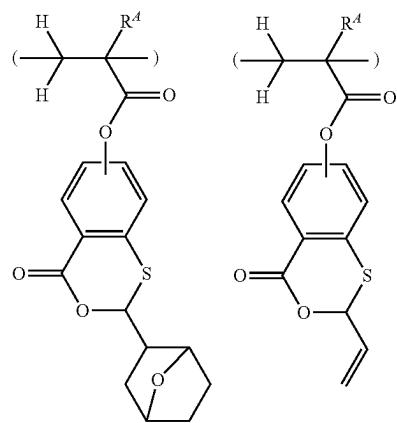
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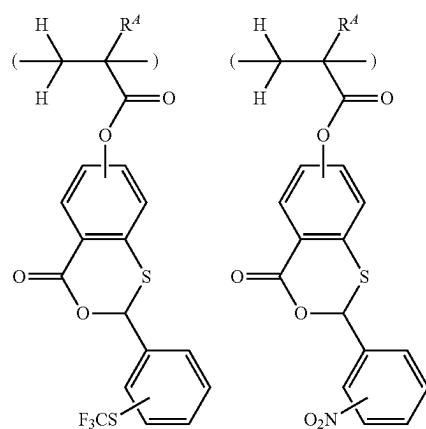
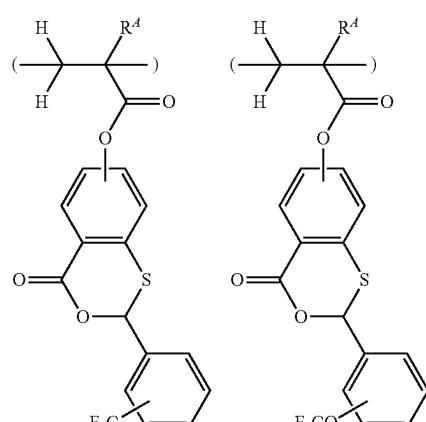
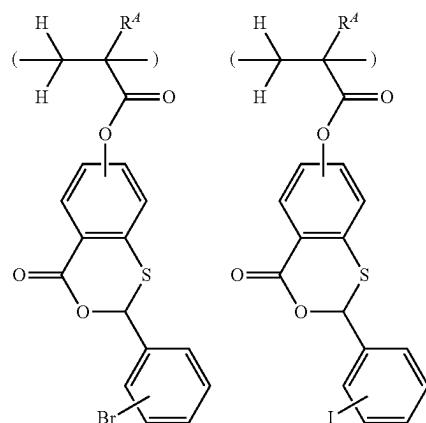
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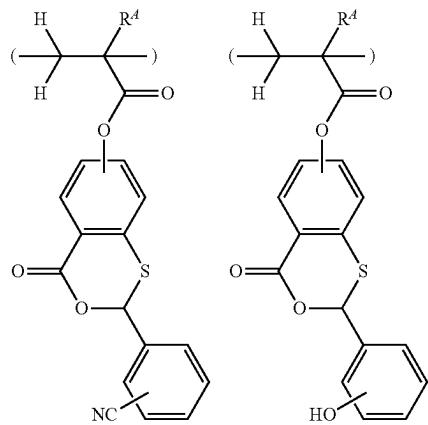
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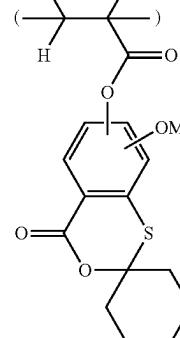
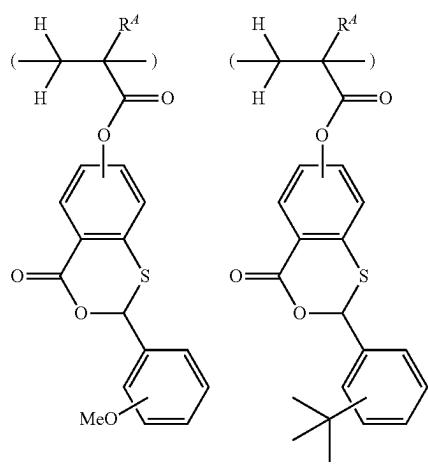
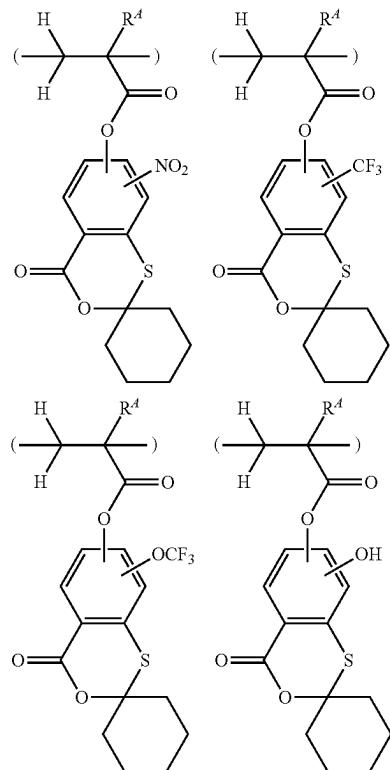
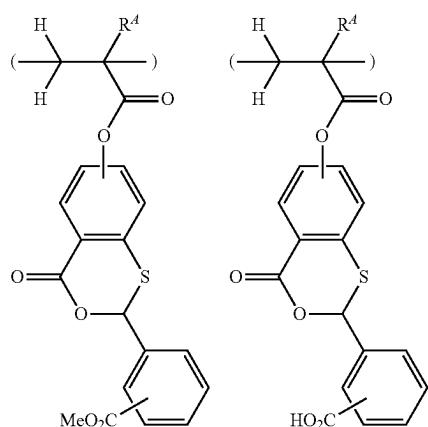
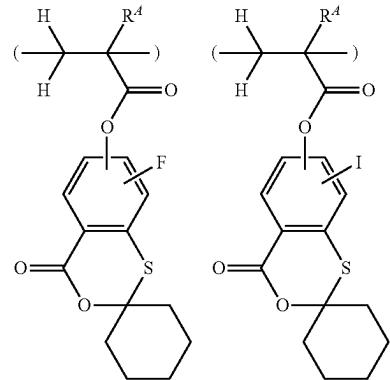
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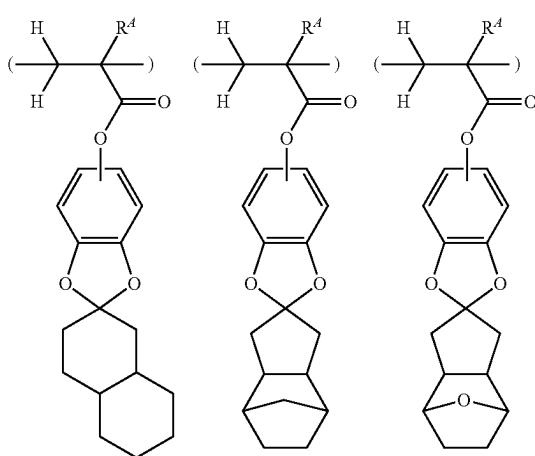
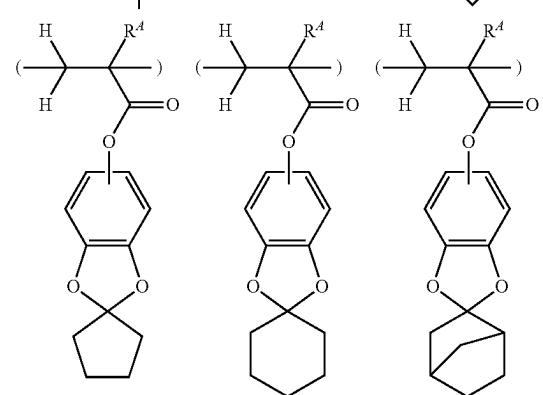
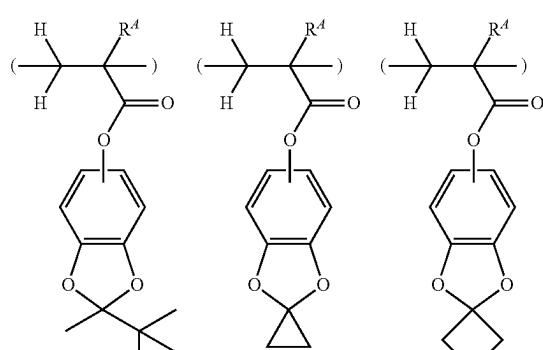
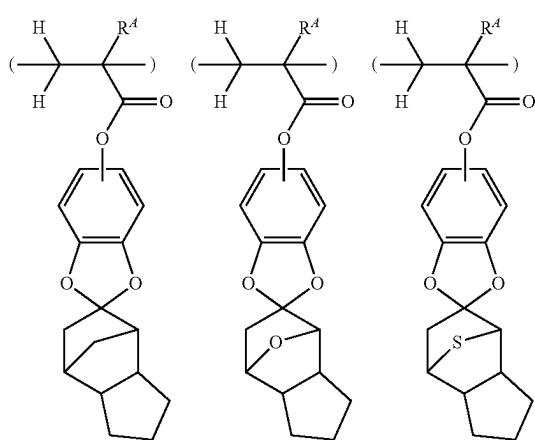
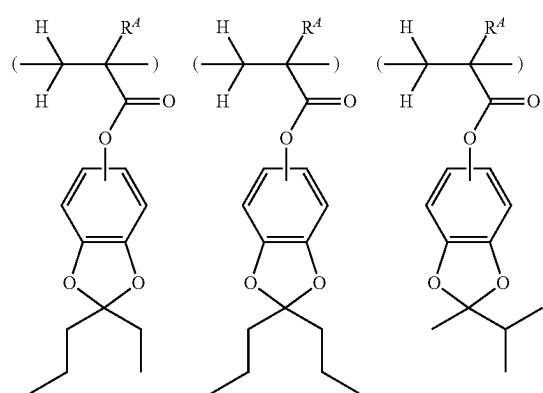
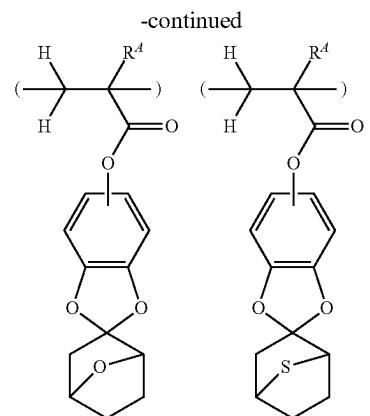
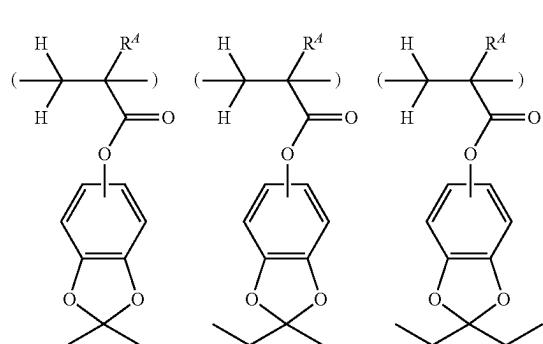


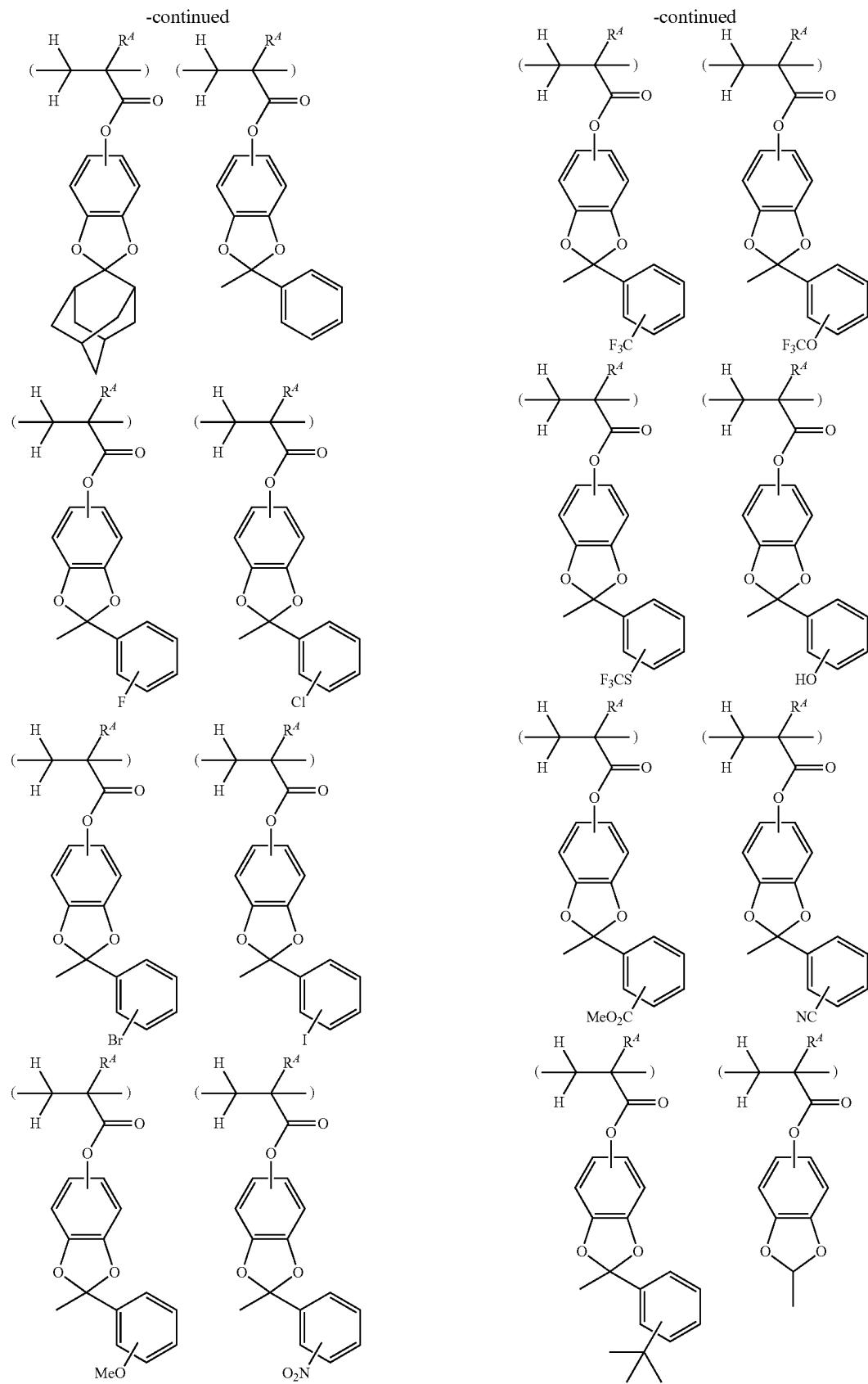
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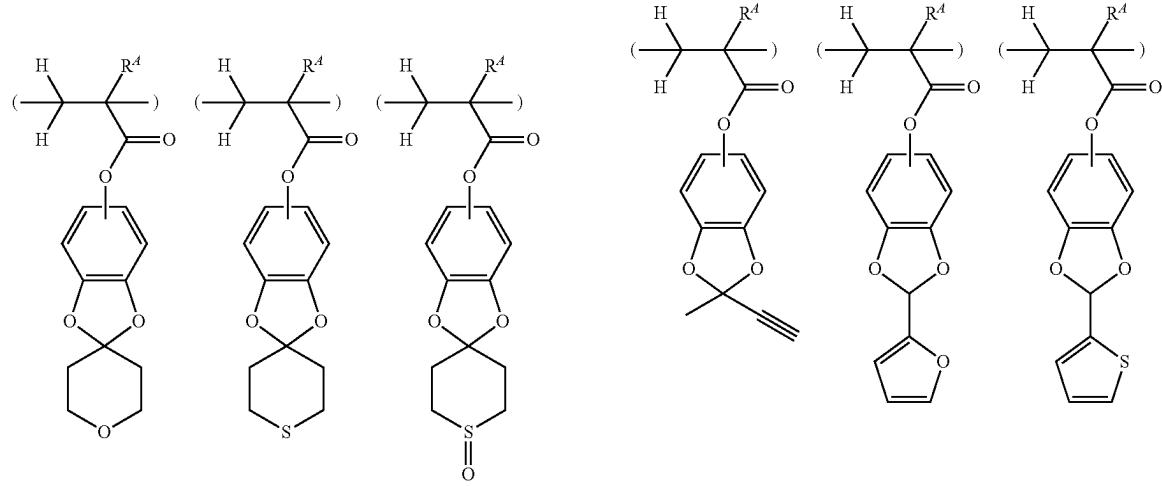
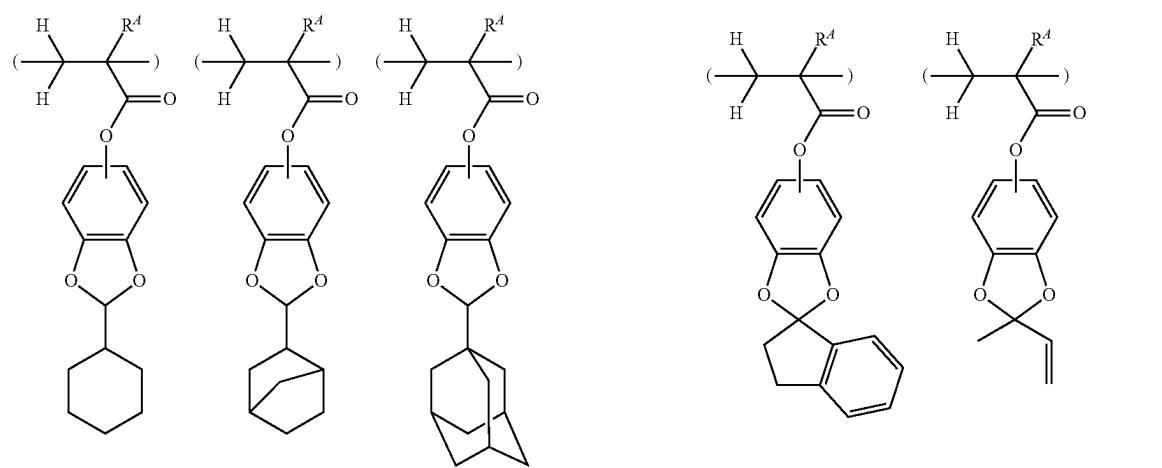
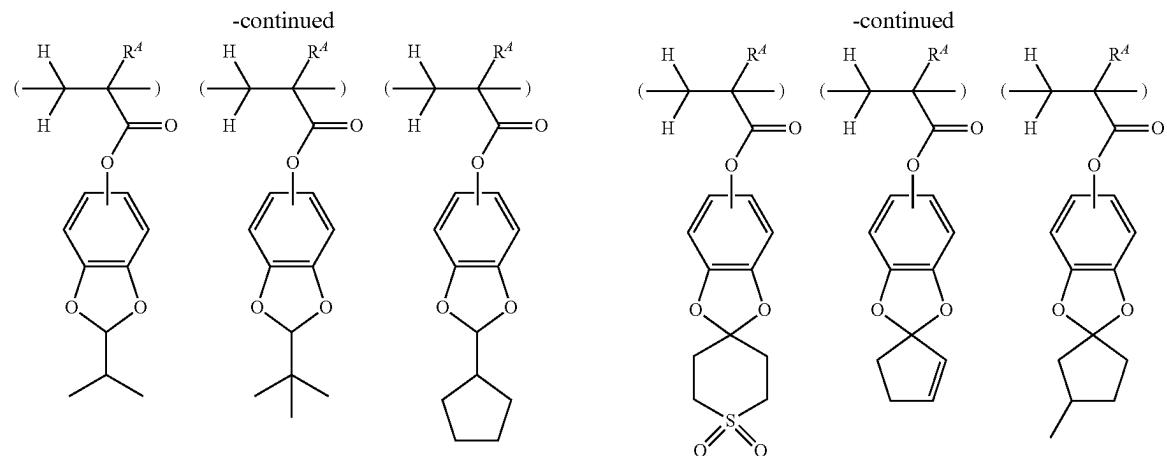


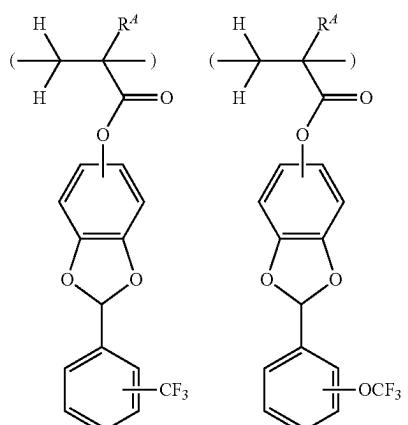
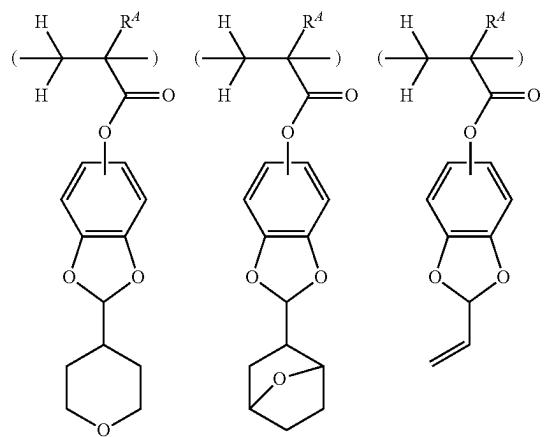
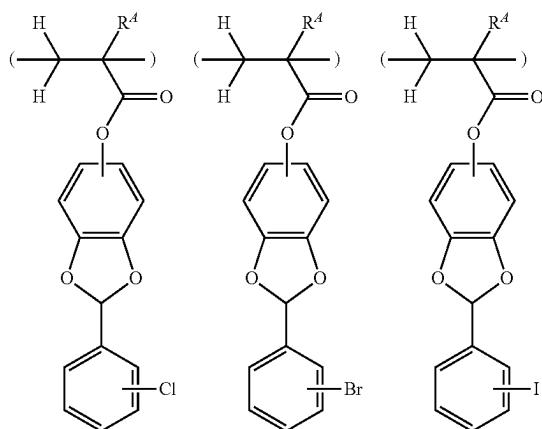
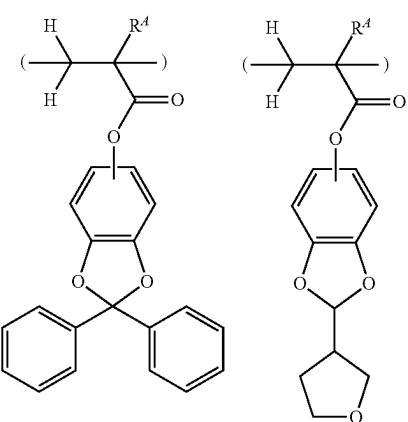
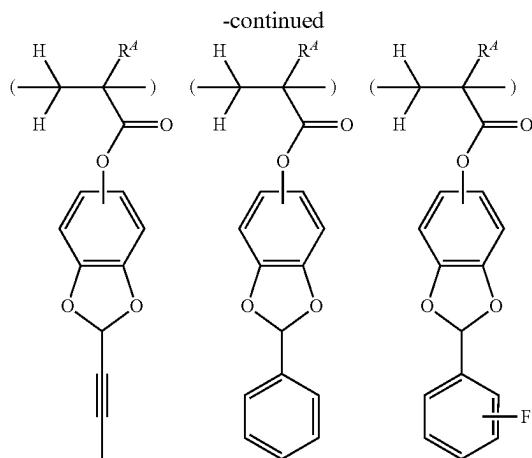
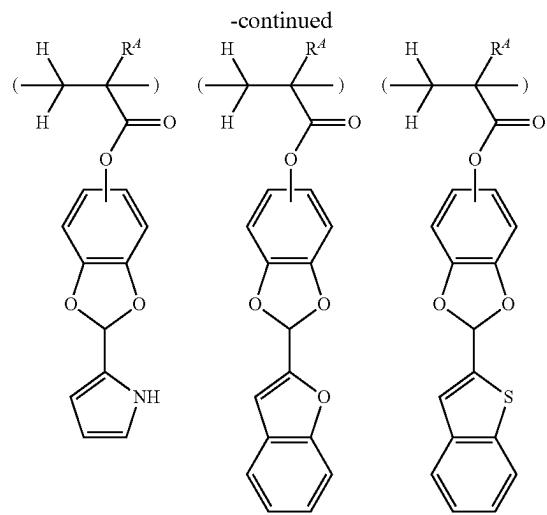
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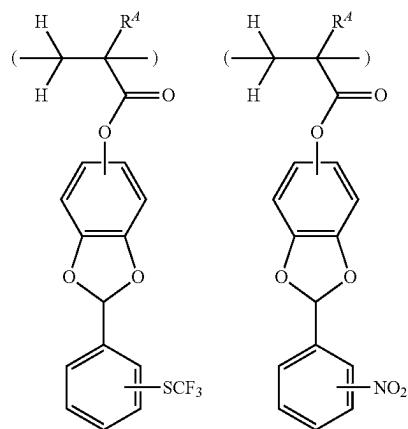




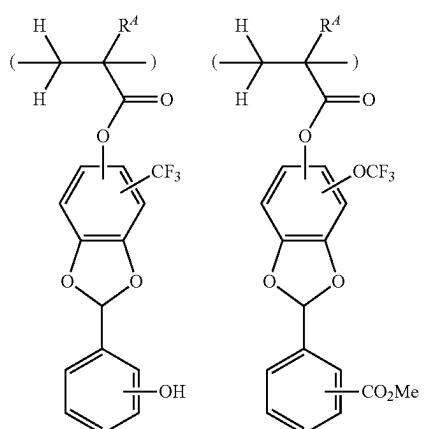
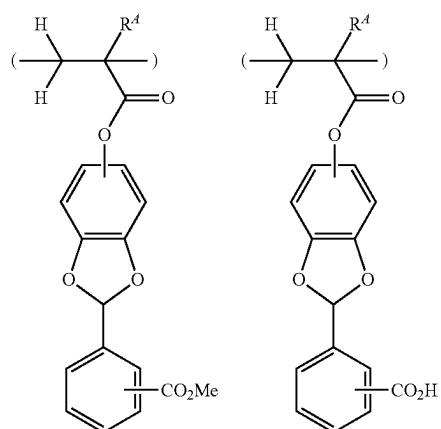
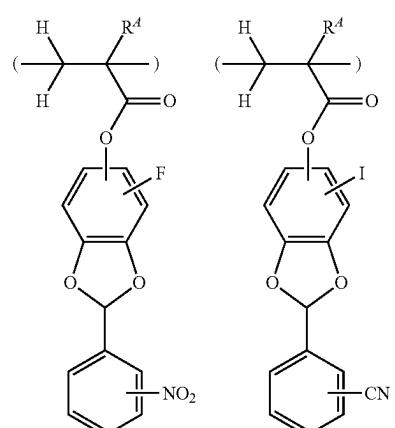
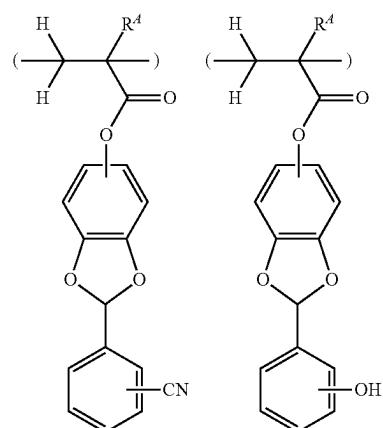
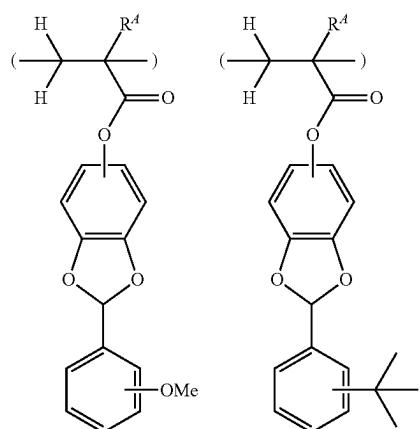




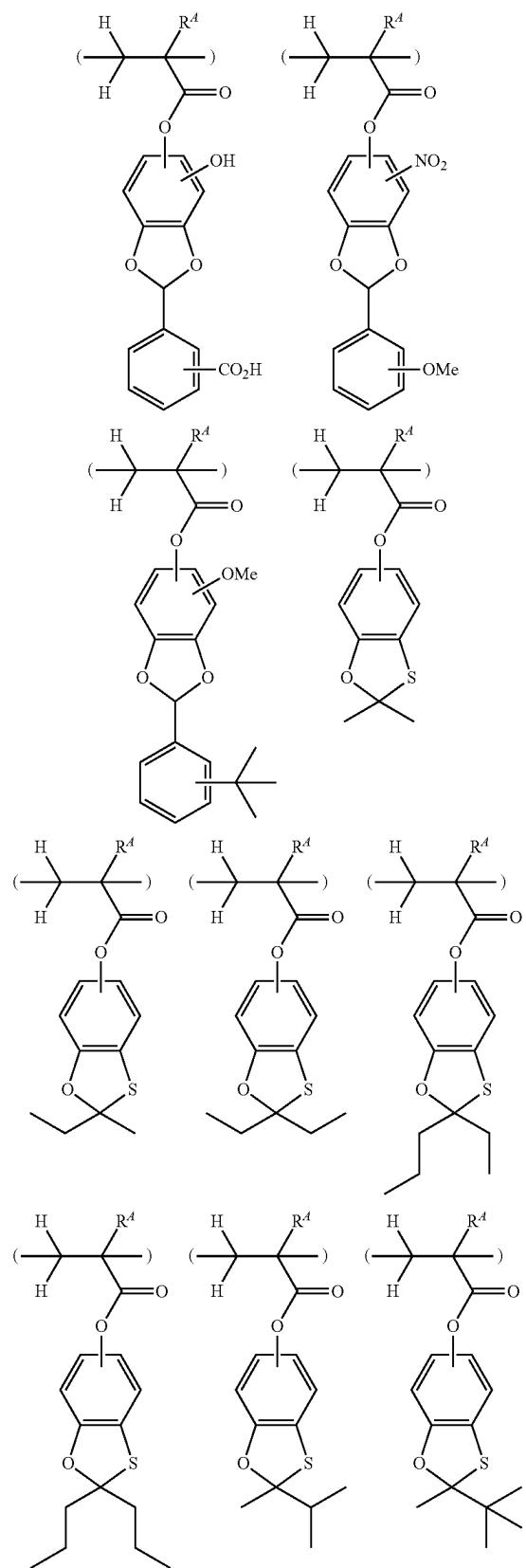
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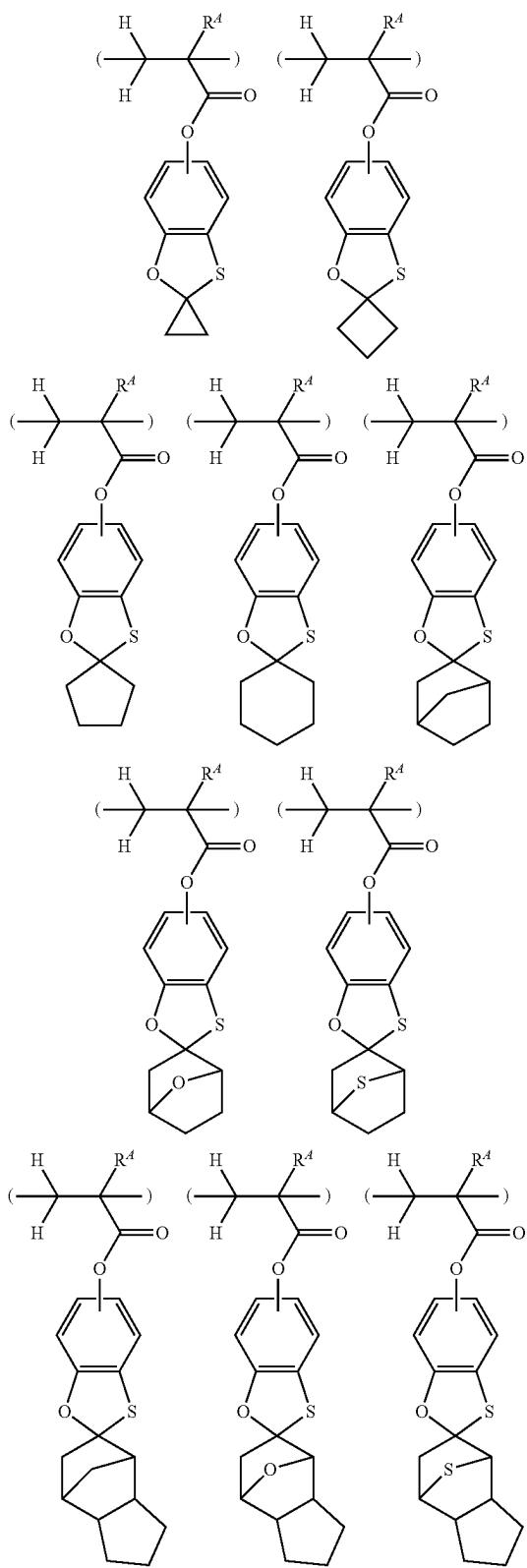
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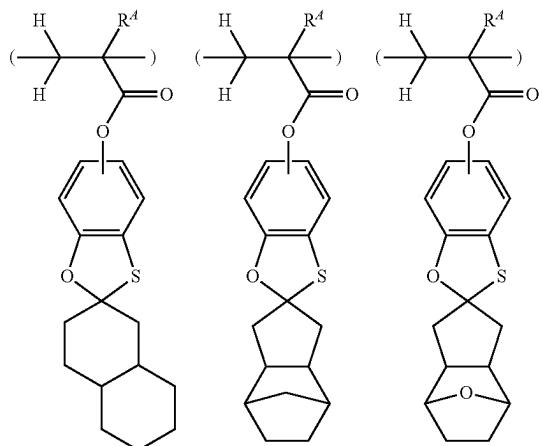
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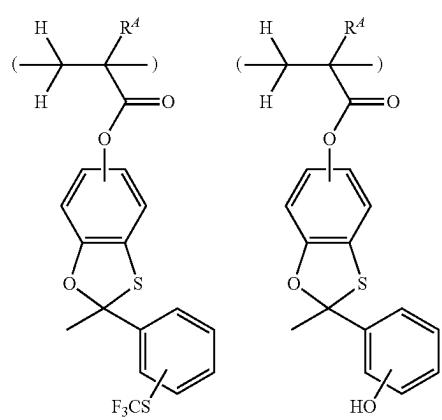
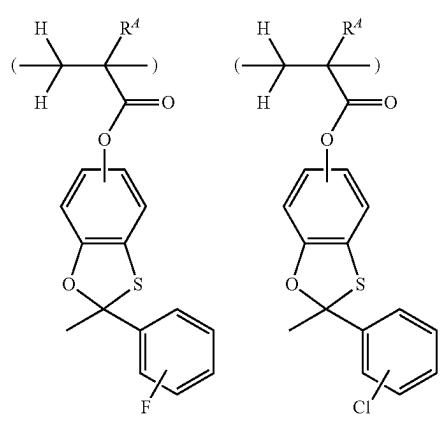
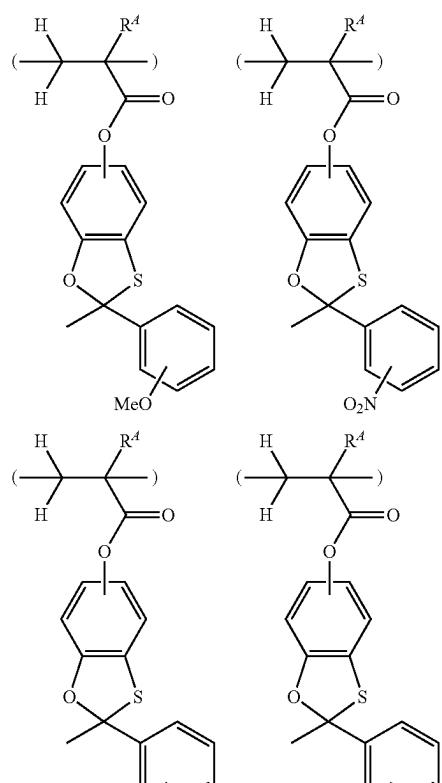
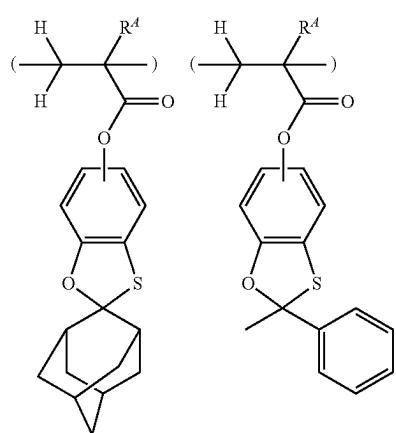
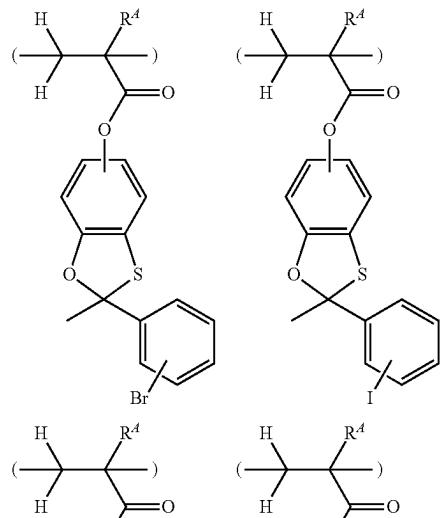
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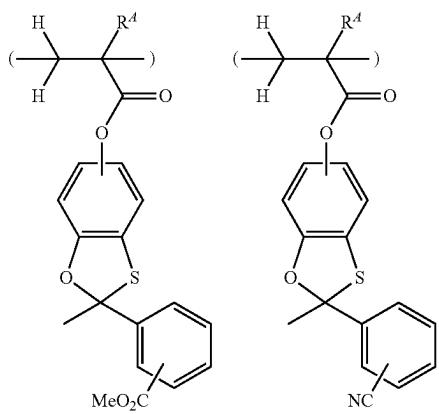
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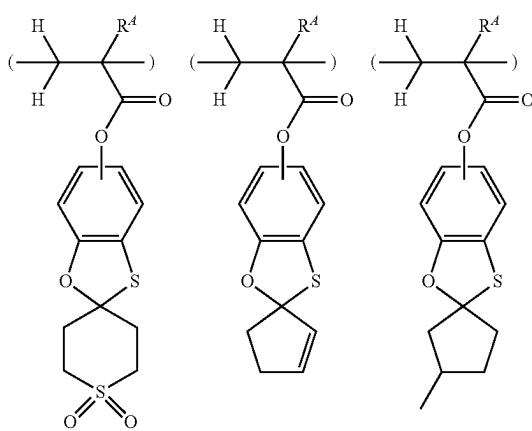
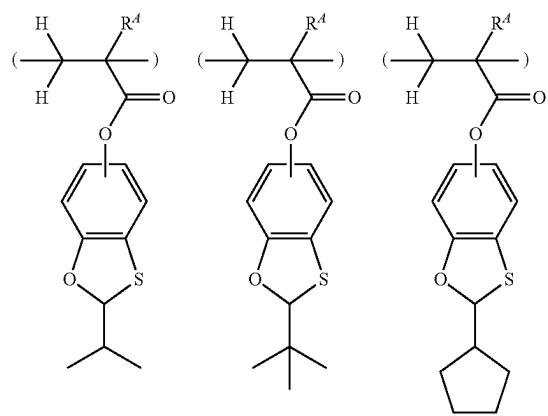
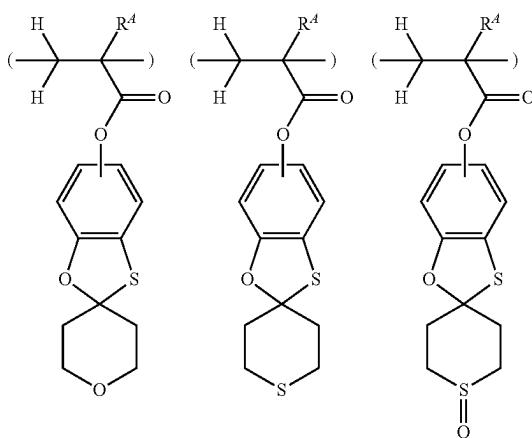
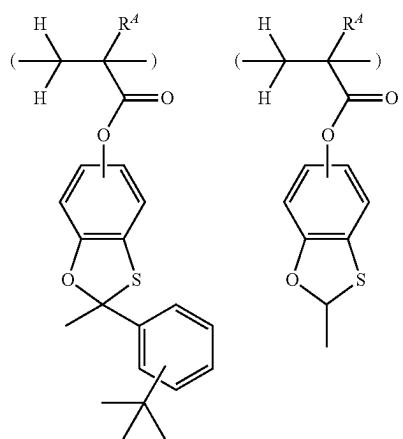
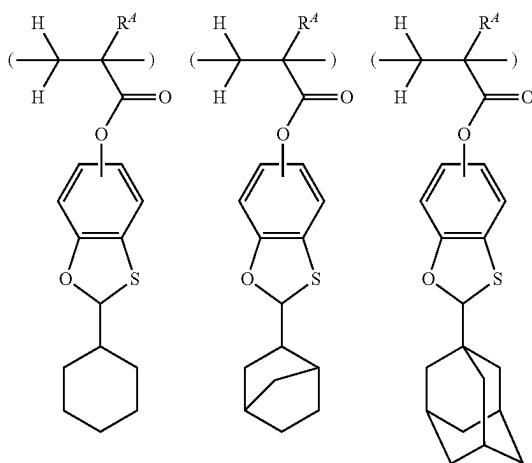
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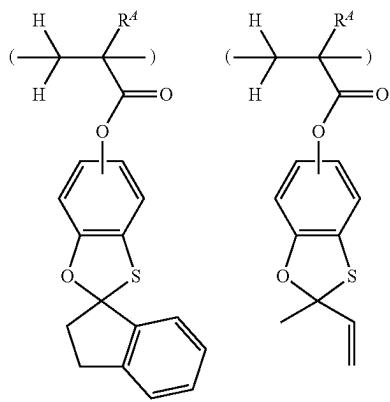
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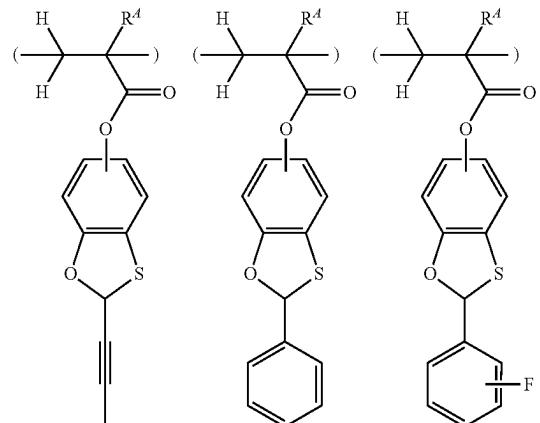
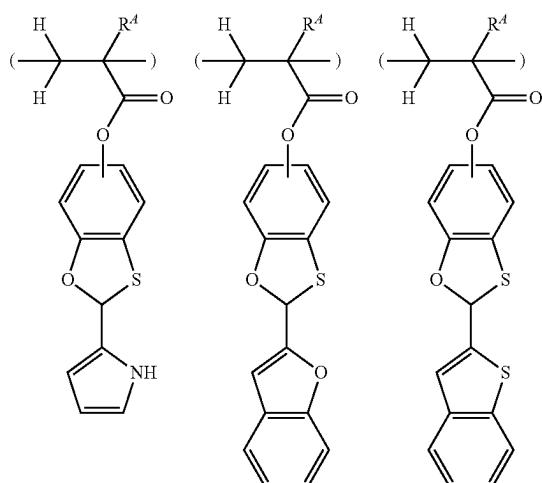
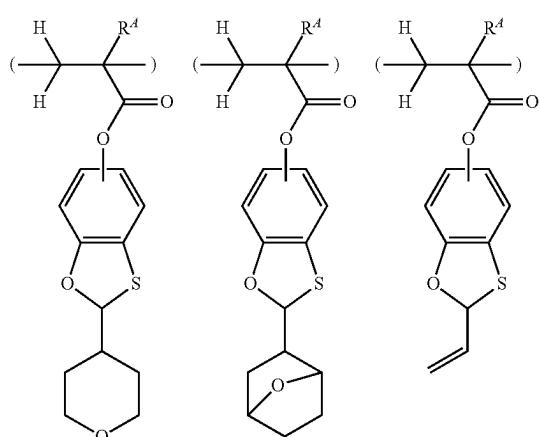
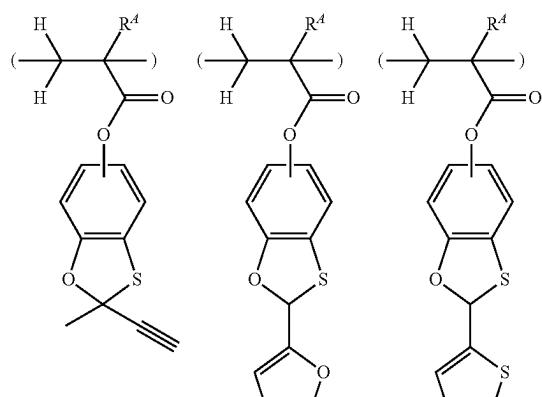
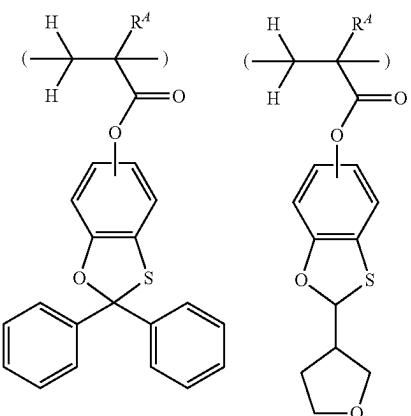
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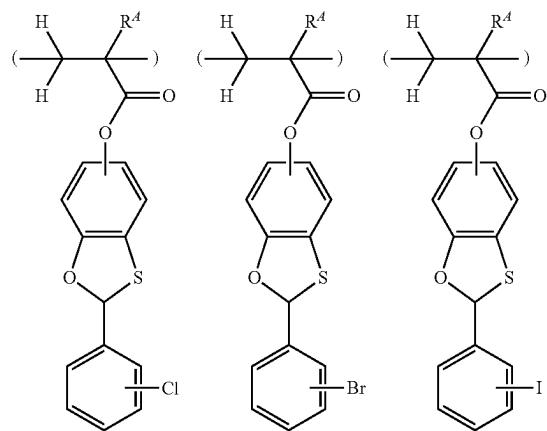
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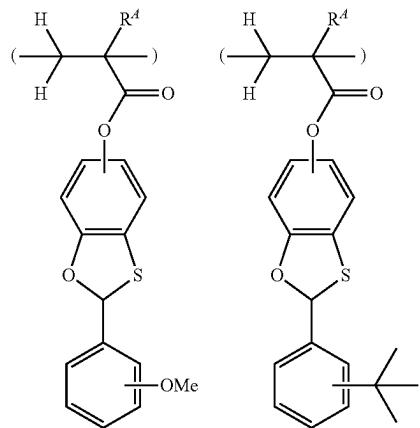
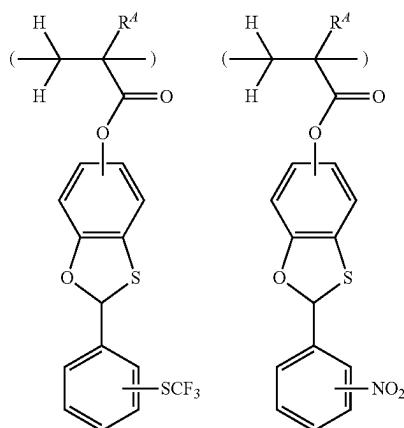
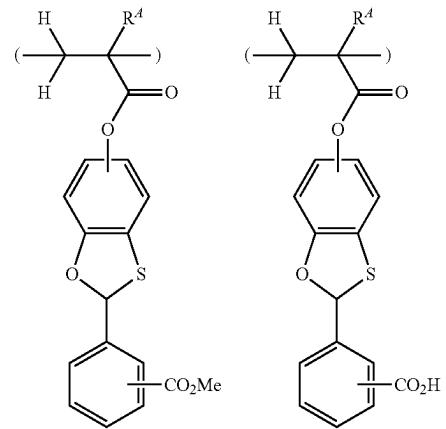
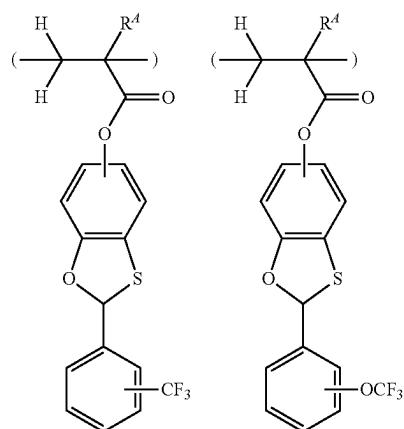
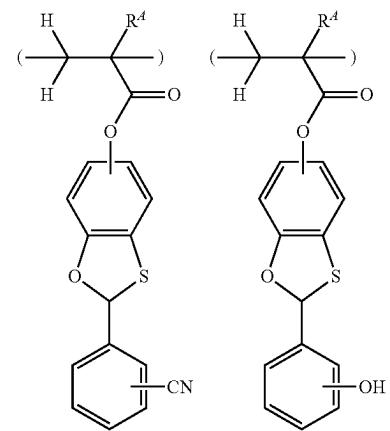
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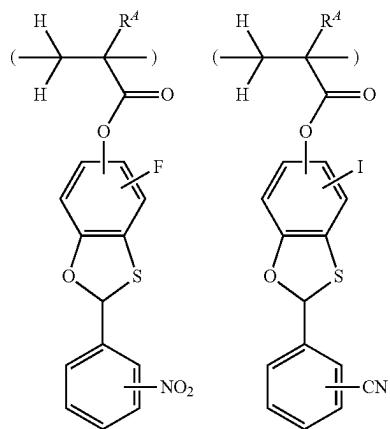
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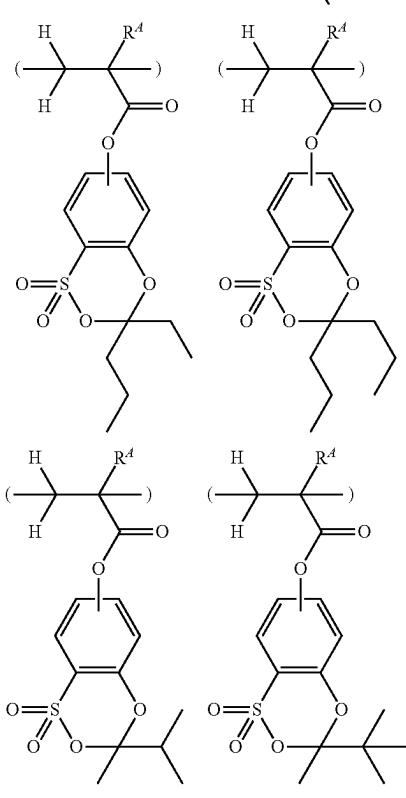
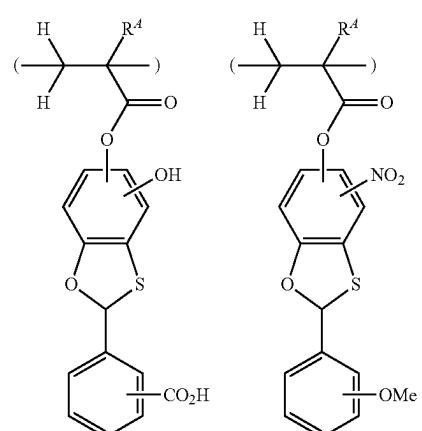
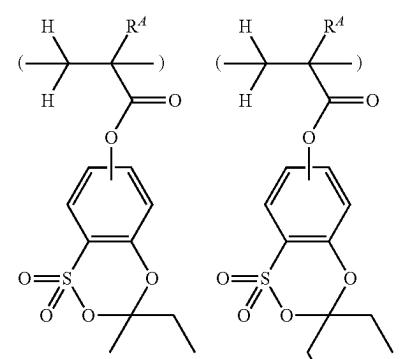
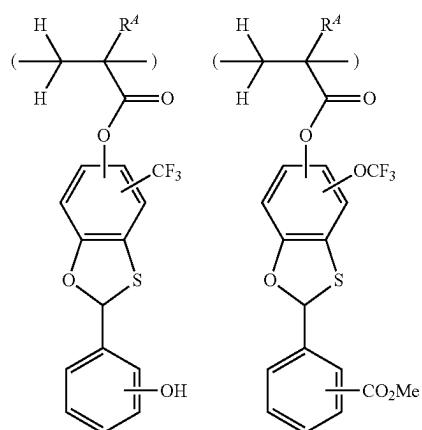
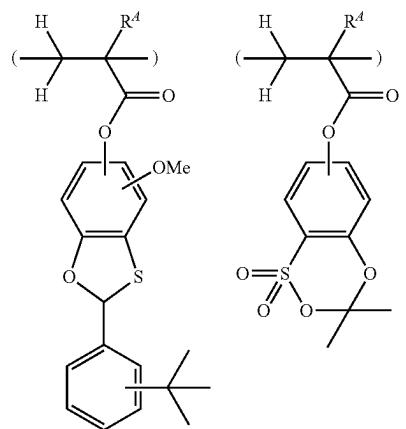
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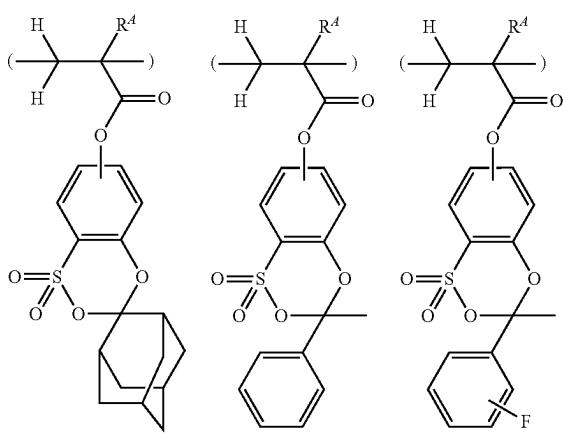
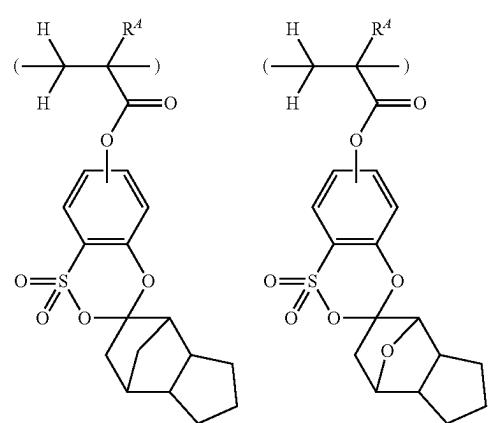
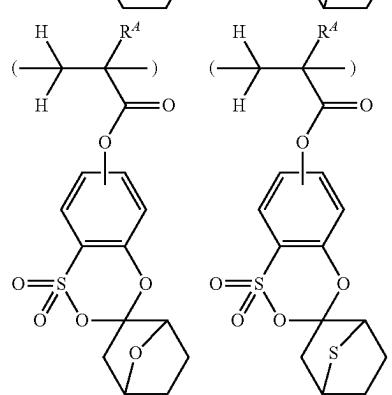
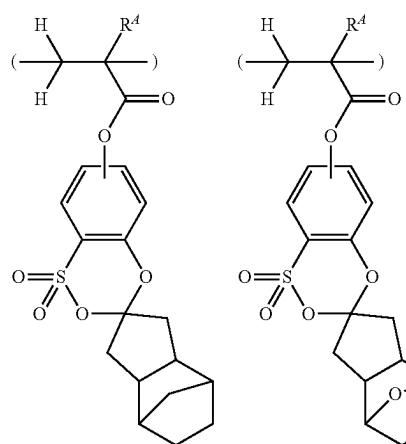
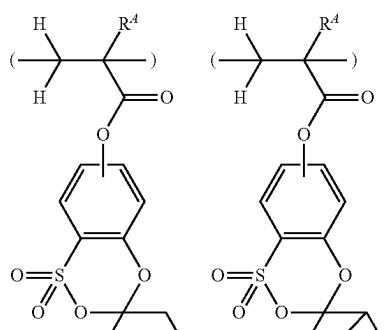
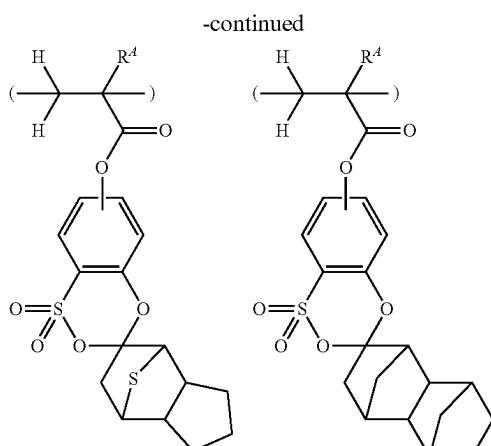
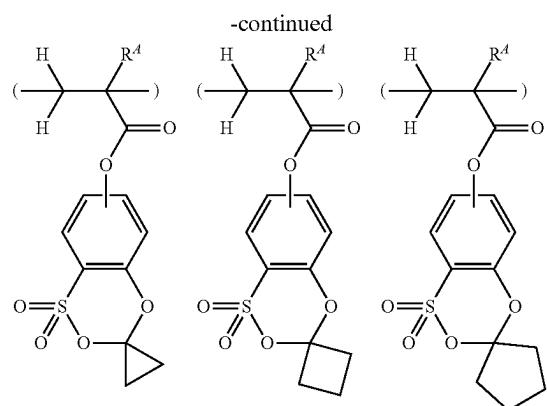


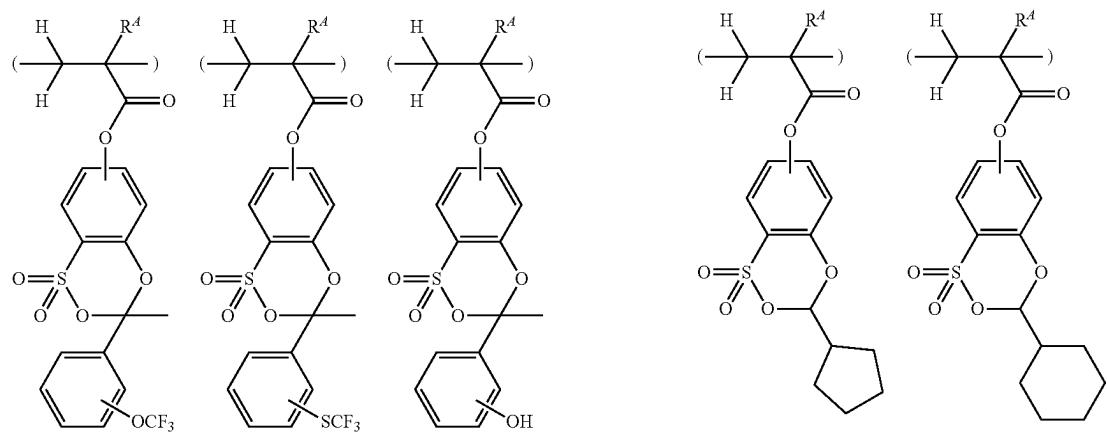
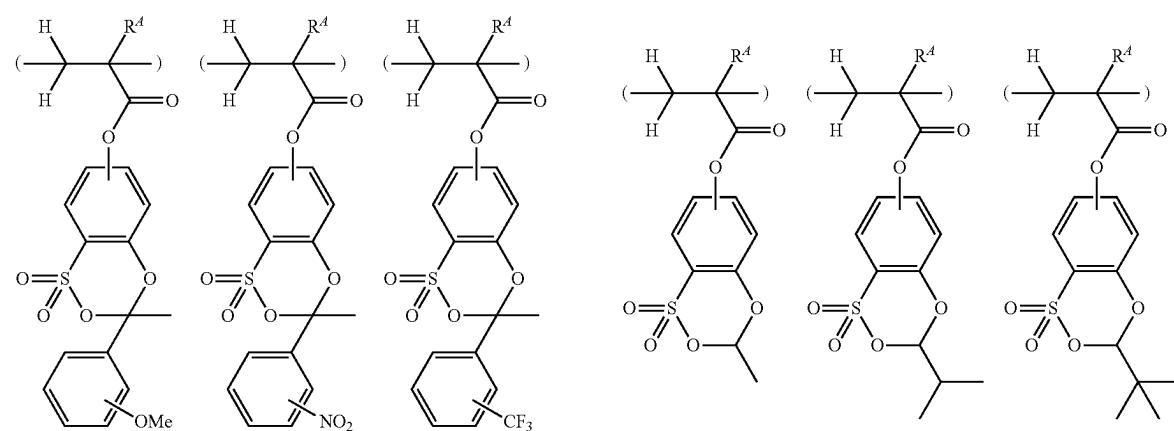
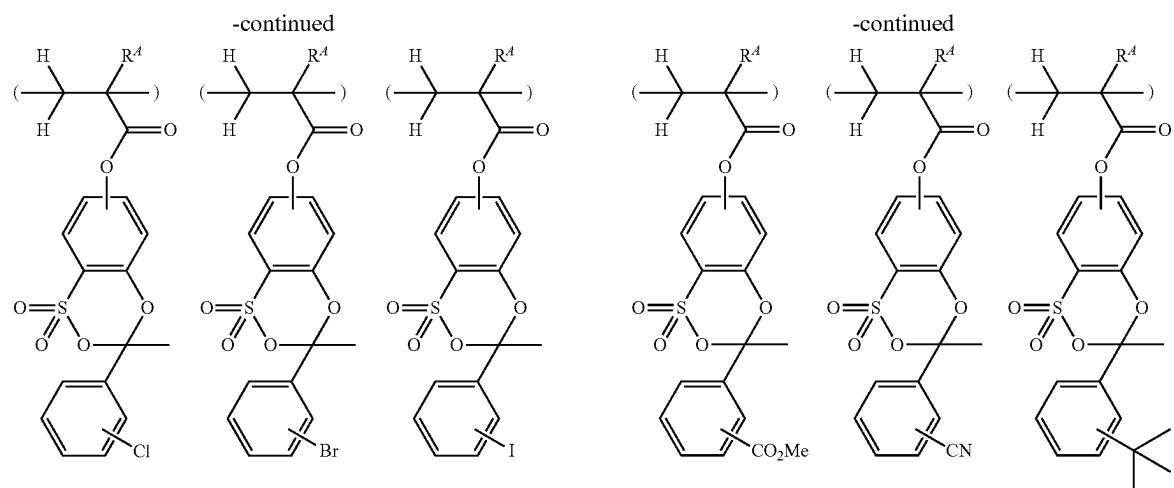
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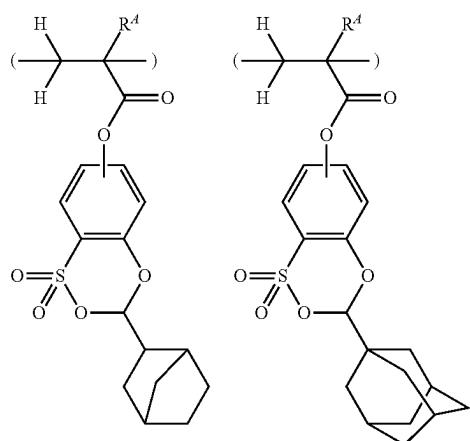
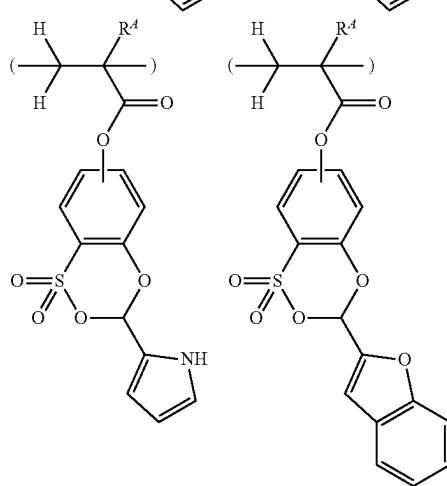
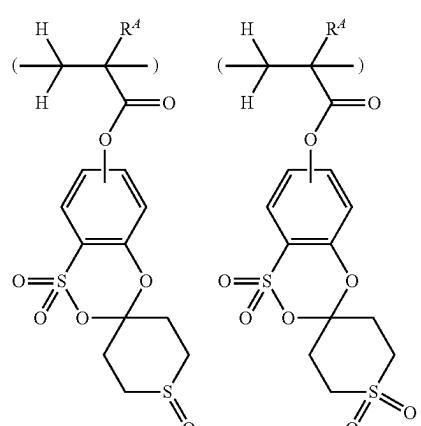
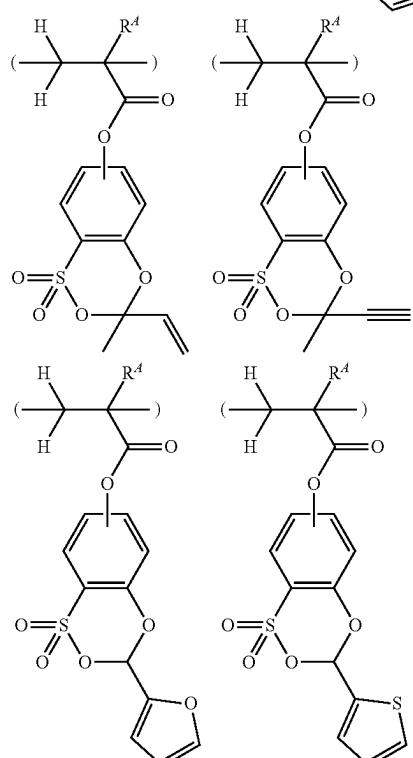
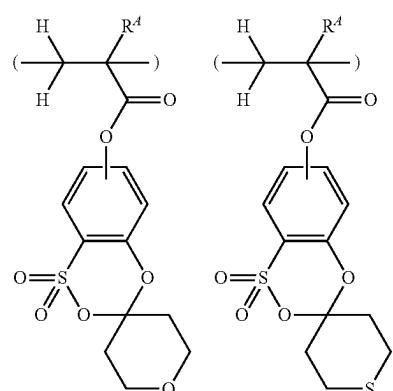
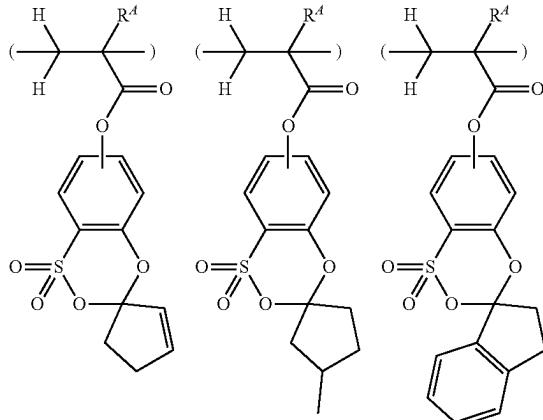


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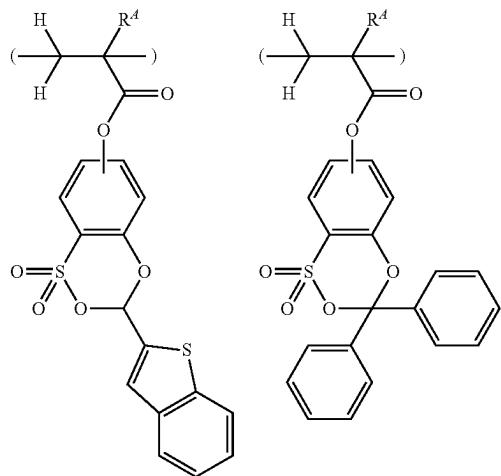




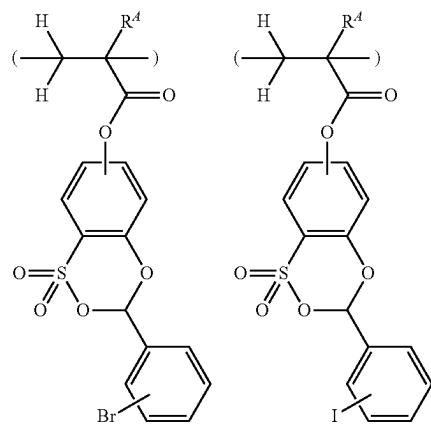
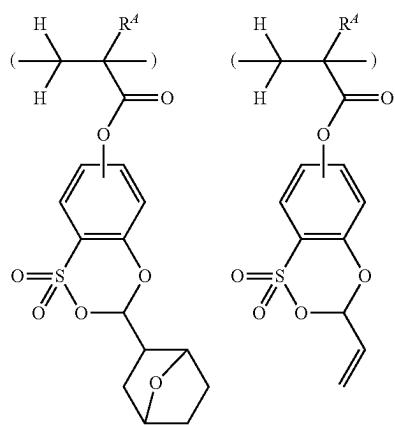
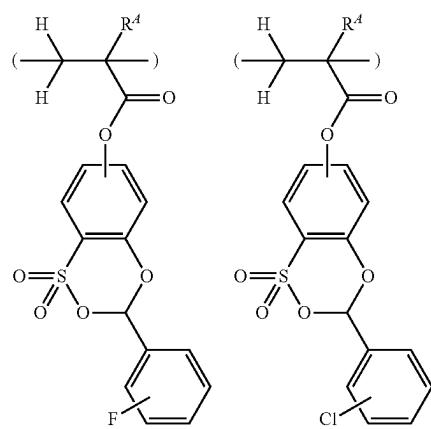
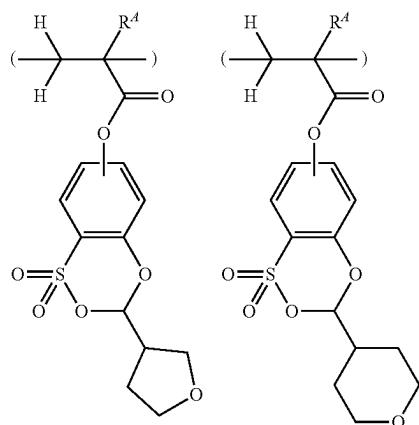
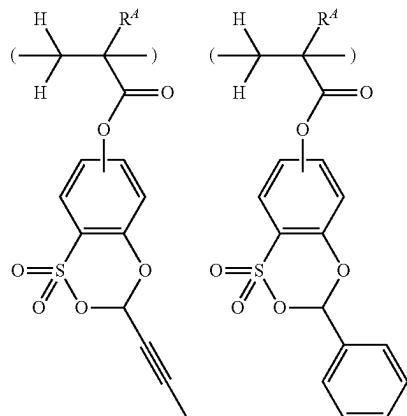


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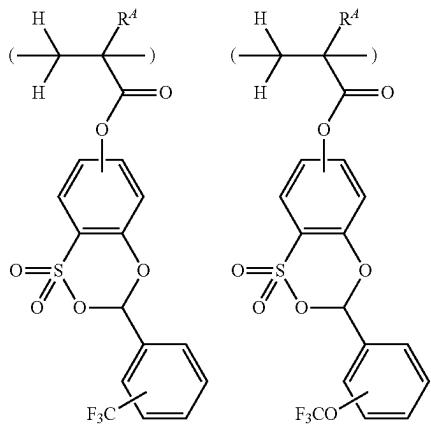
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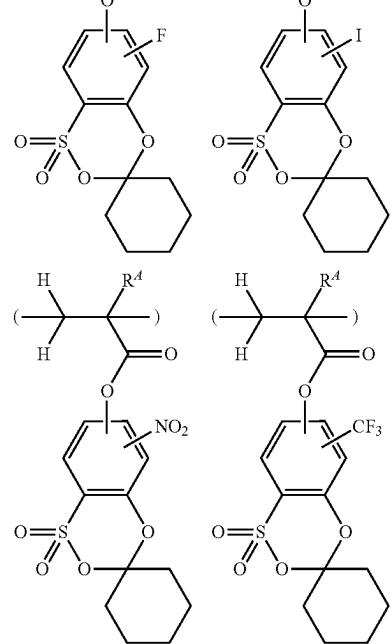
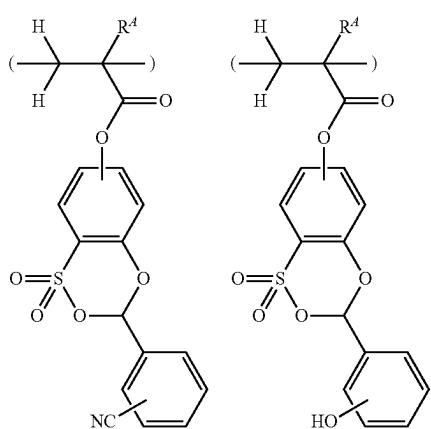
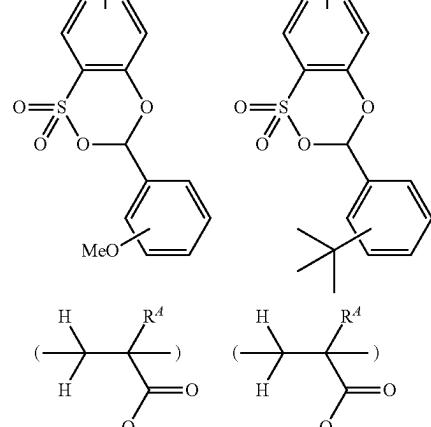
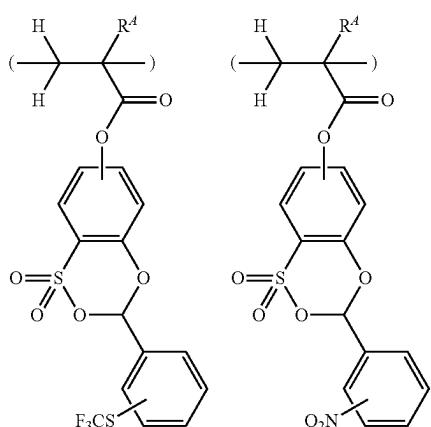
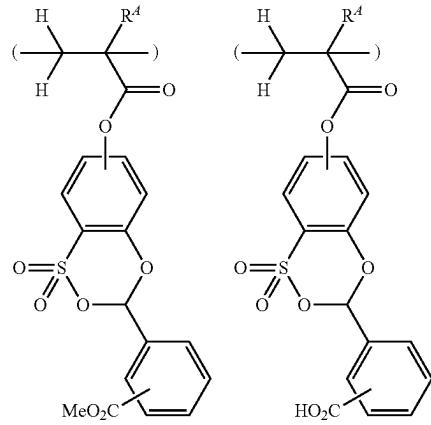
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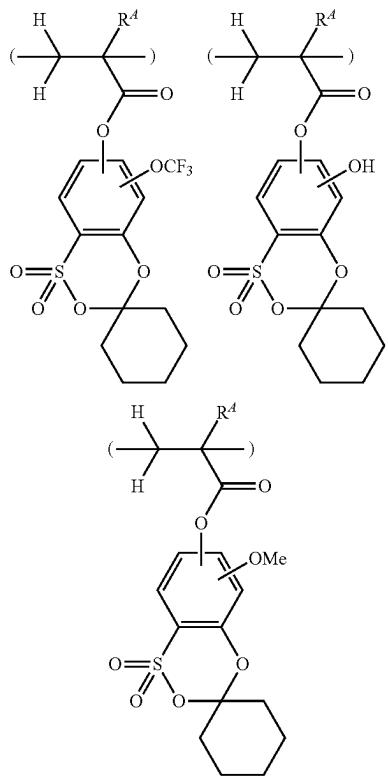
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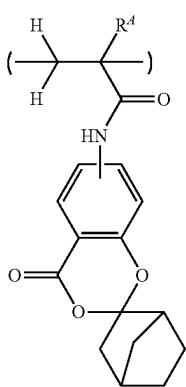
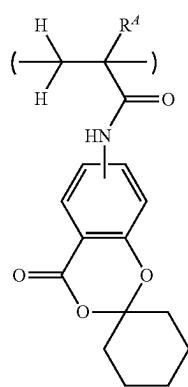
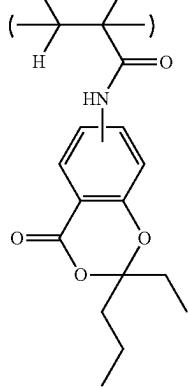
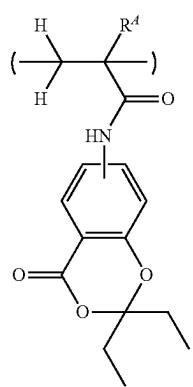
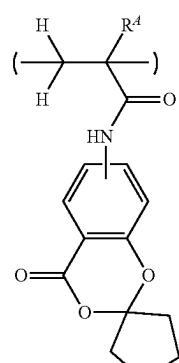
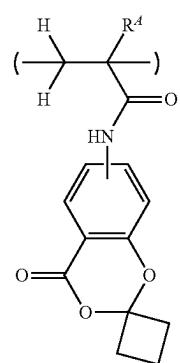
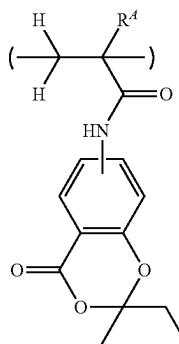
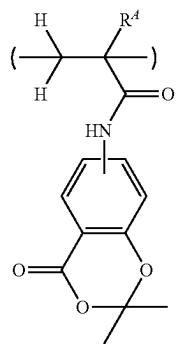
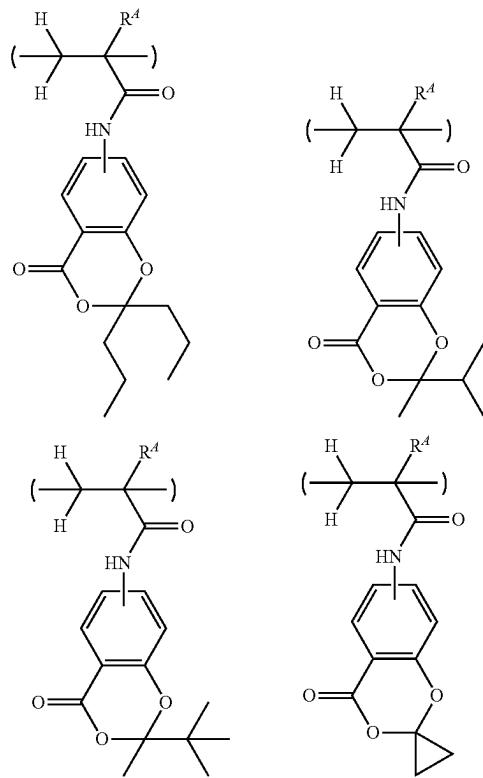
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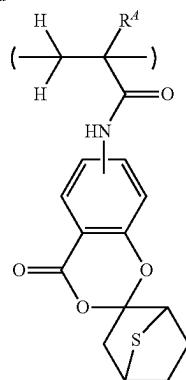
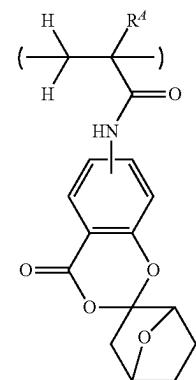
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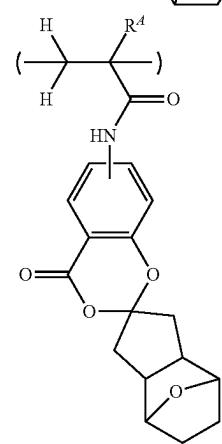
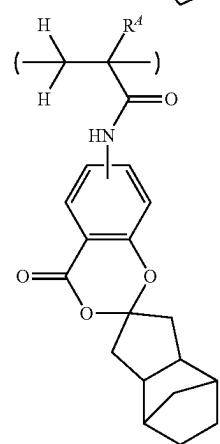
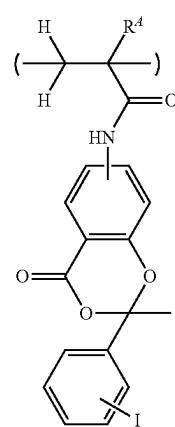
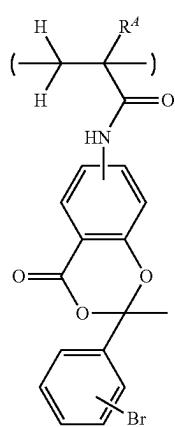
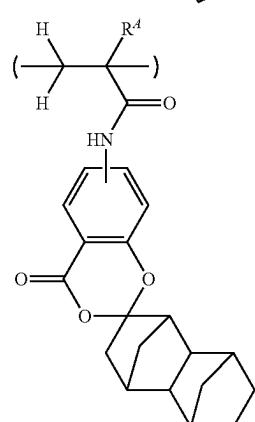
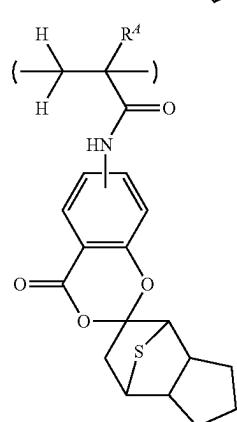
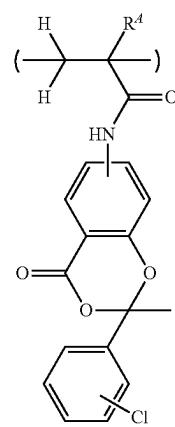
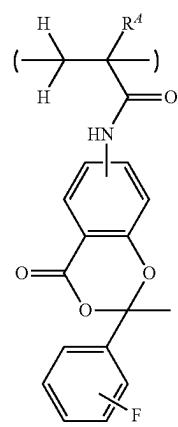
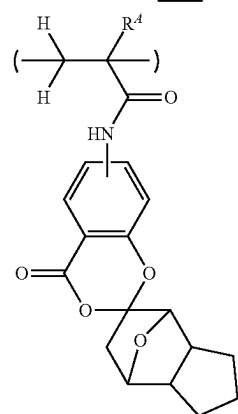
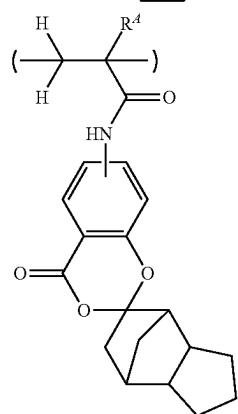
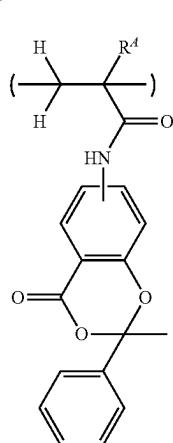
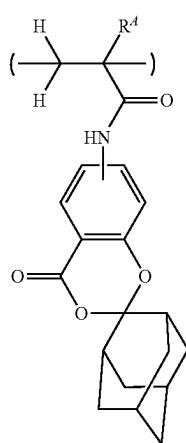
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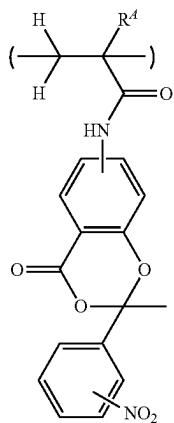
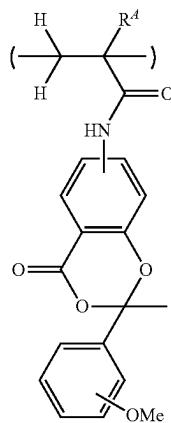
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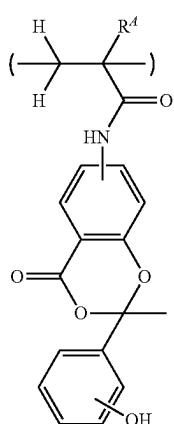
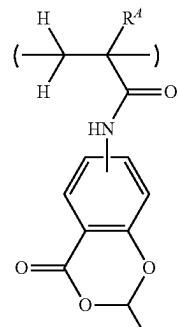
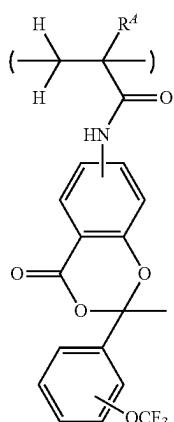
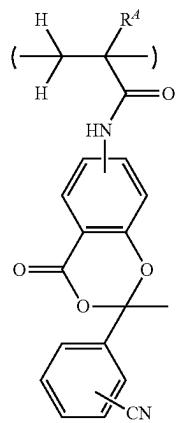
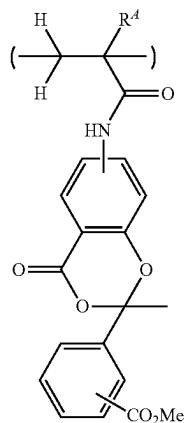
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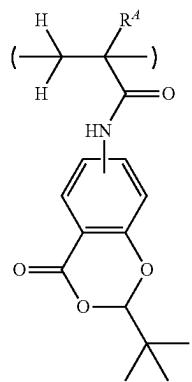
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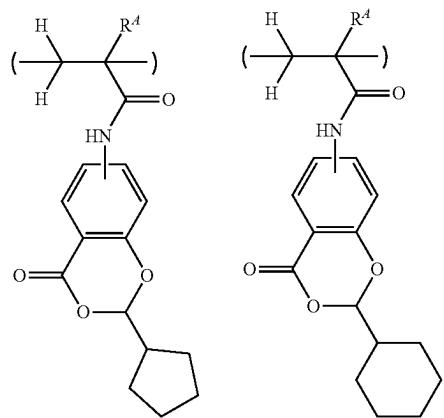
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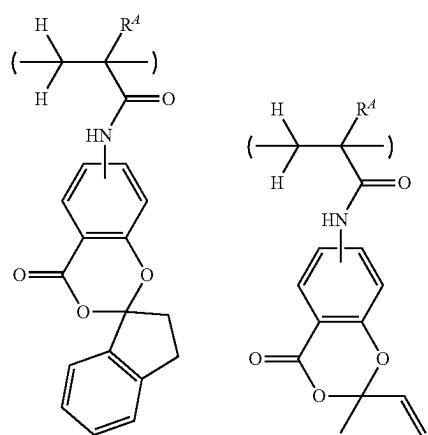
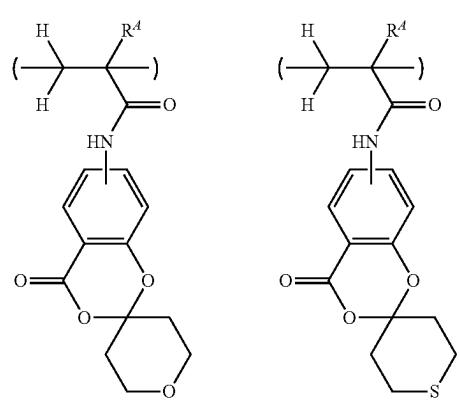
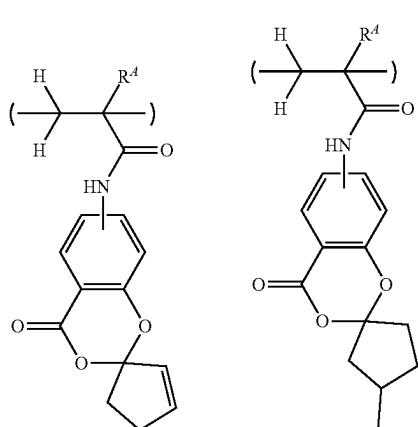
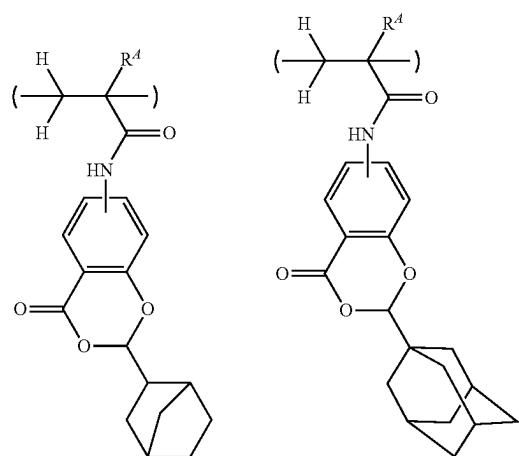
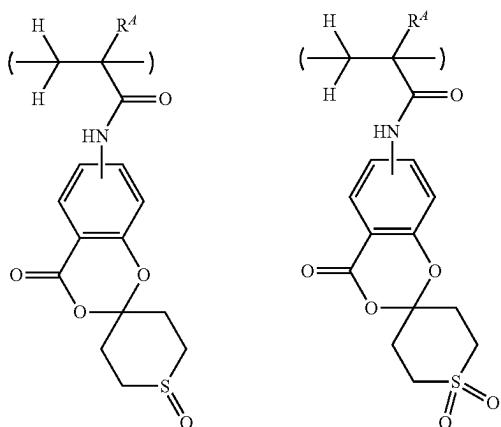
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 | \qquad \qquad \qquad \qquad | \\
 \text{H} \qquad \qquad \qquad \text{R}^A \\
 | \\
 \text{H} \\
 \text{HN} \\
 | \\
 \text{---} \text{C}_6\text{H}_3\text{---} \text{C}_6\text{H}_3\text{---} \\
 | \qquad \qquad \qquad | \\
 \text{O} \qquad \qquad \qquad \text{O} \\
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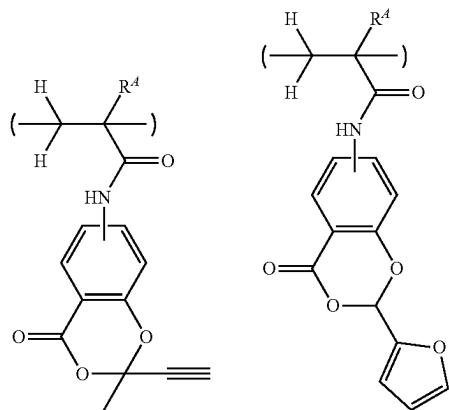
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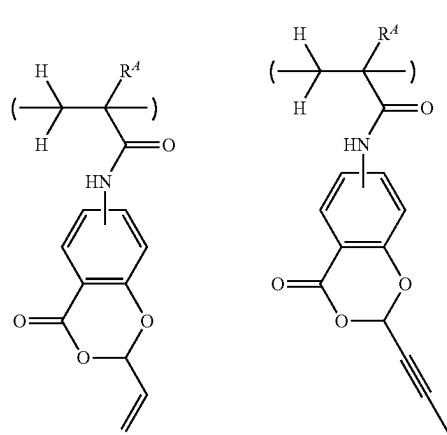
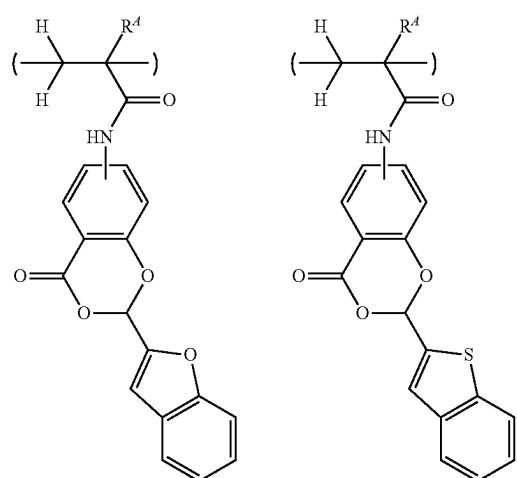
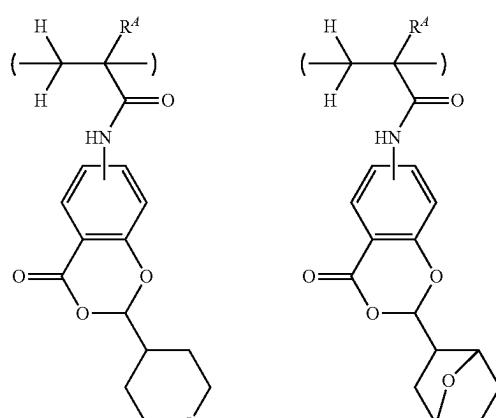
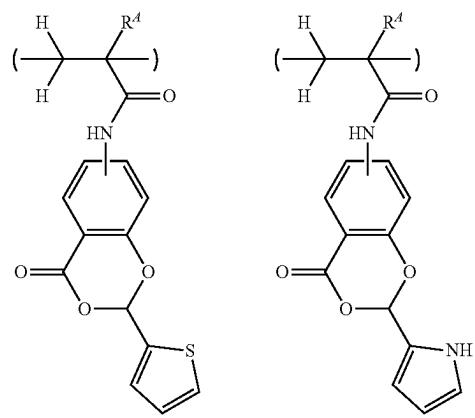
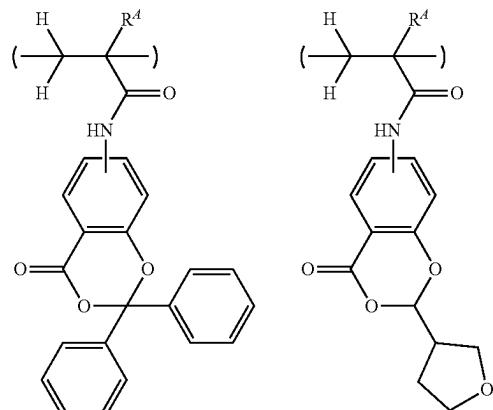
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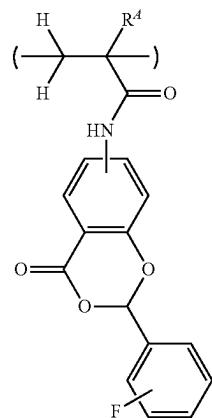
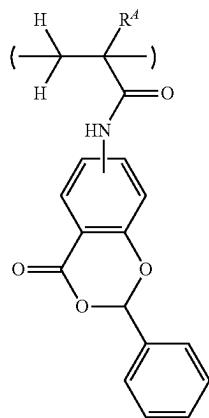
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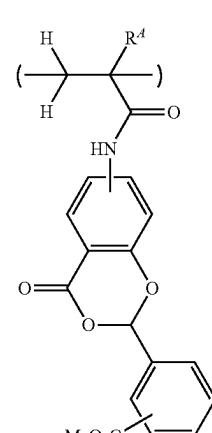
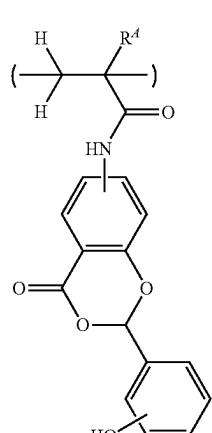
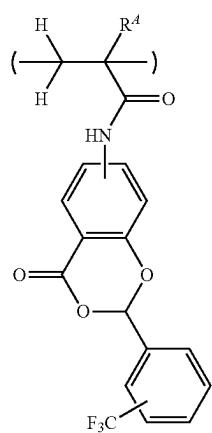
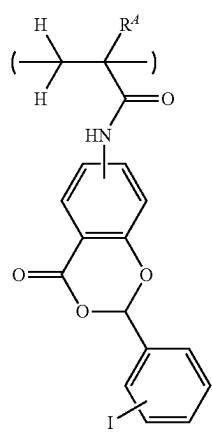
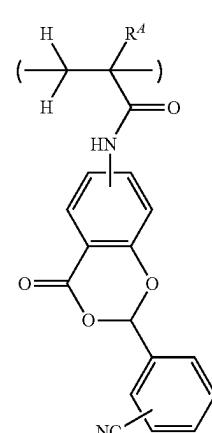
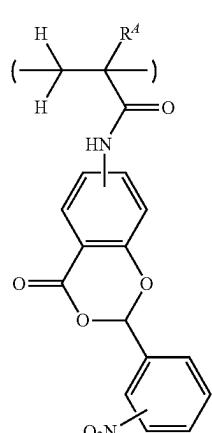
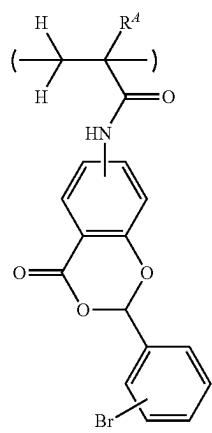
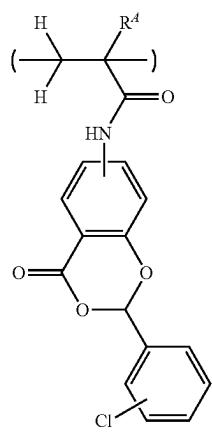
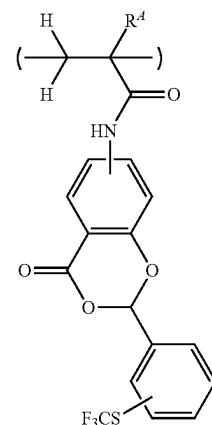
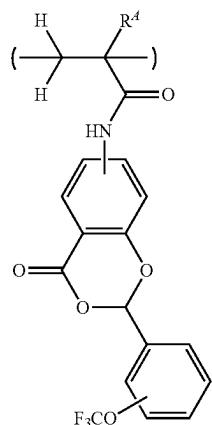
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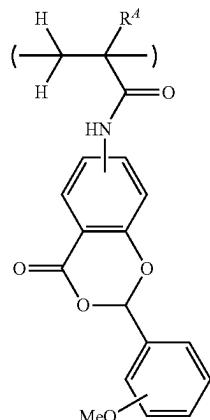
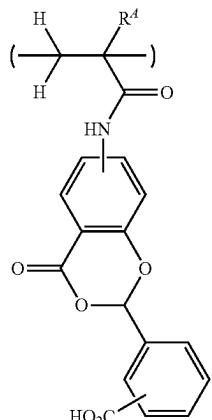
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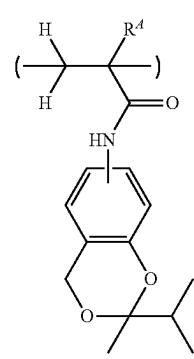
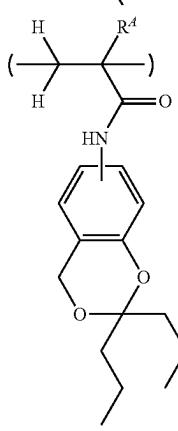
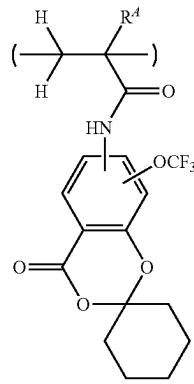
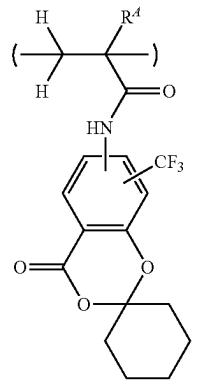
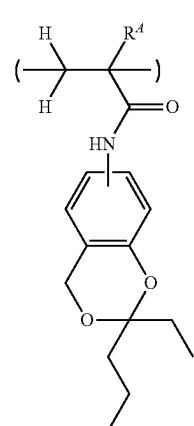
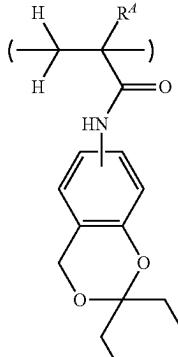
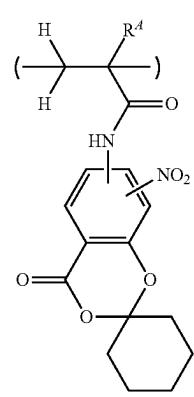
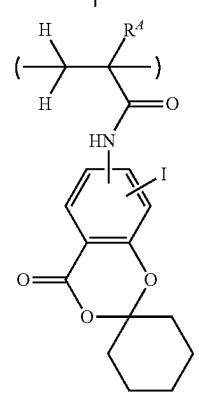
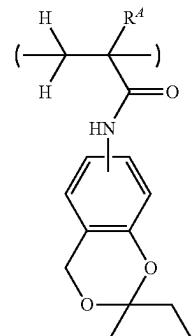
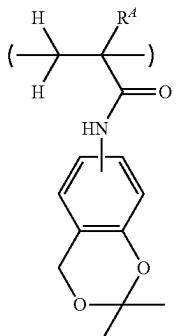
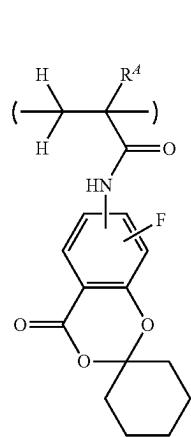
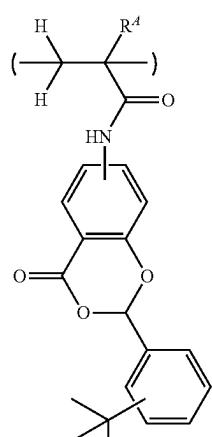
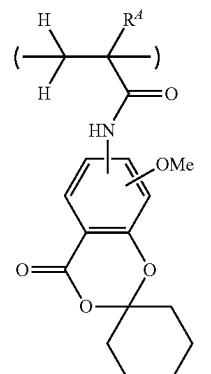
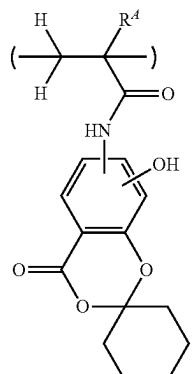
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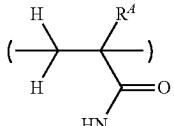
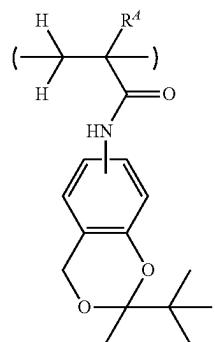
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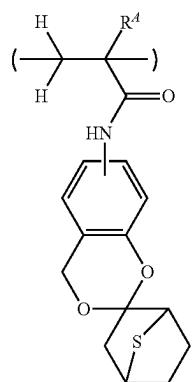
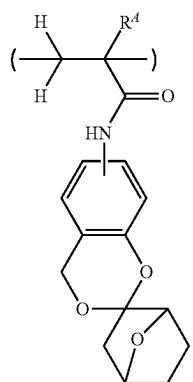
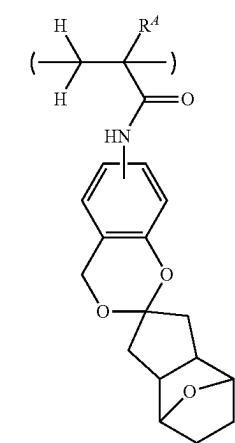
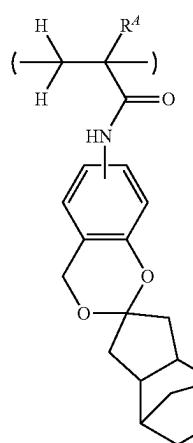
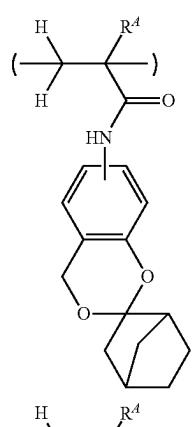
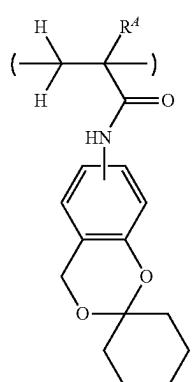
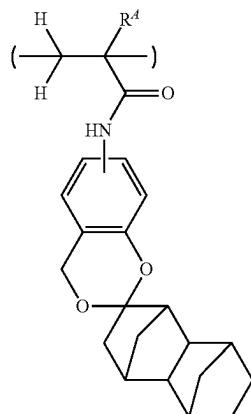
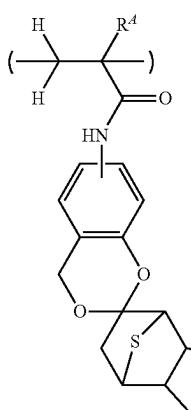
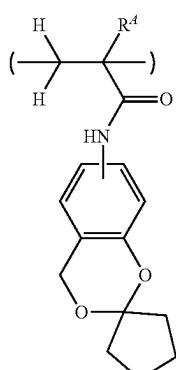
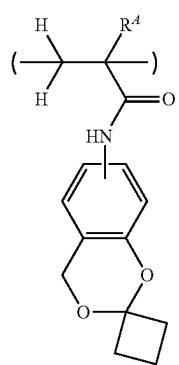
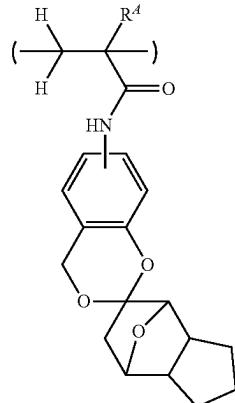
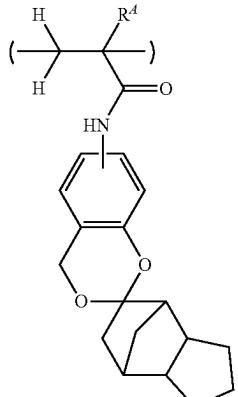
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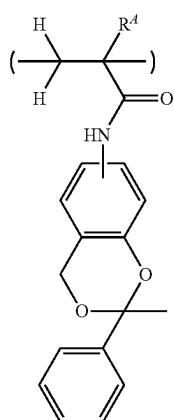
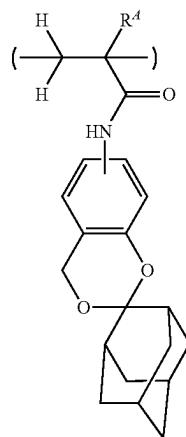
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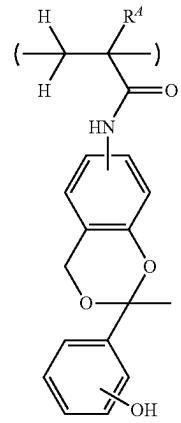
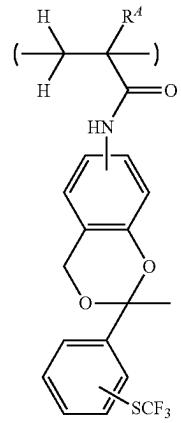
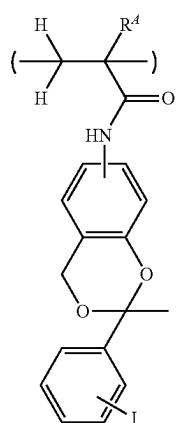
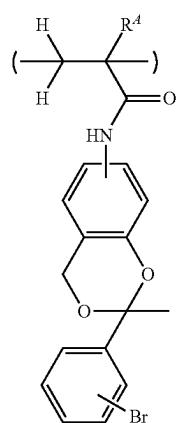
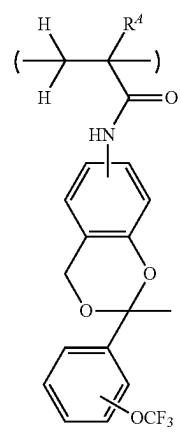
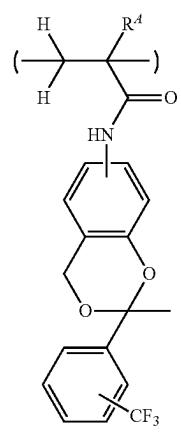
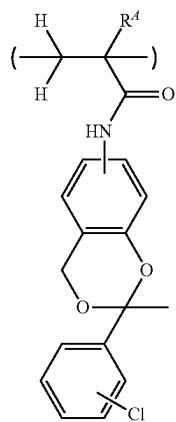
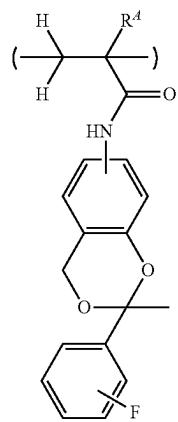
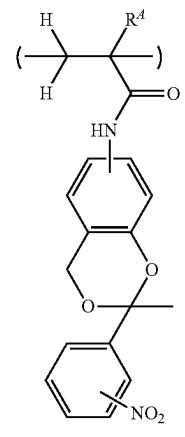
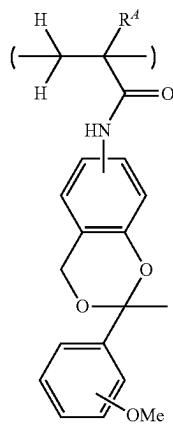
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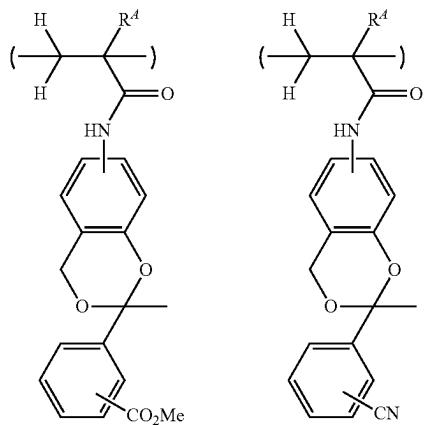
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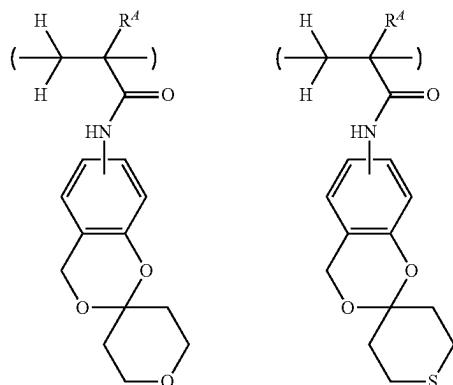
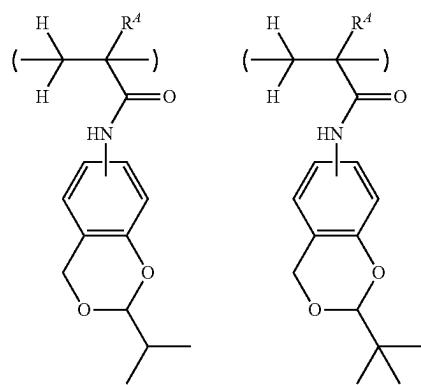
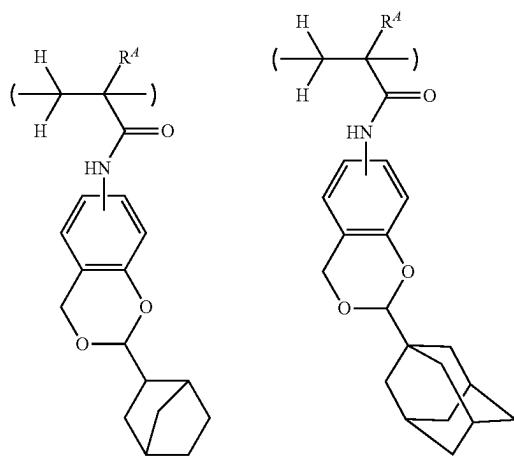
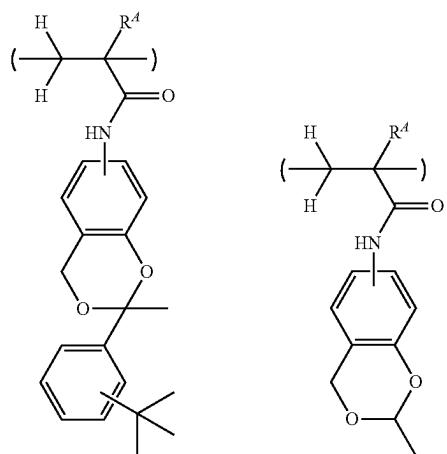
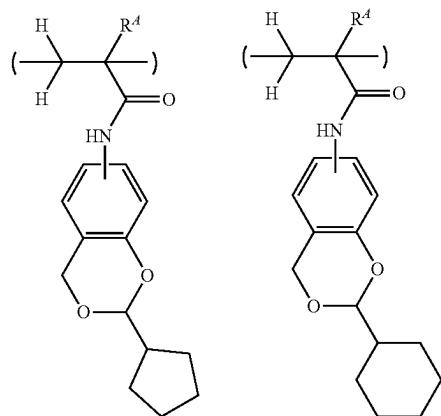
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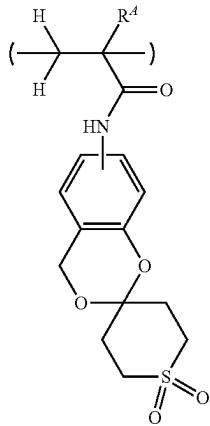
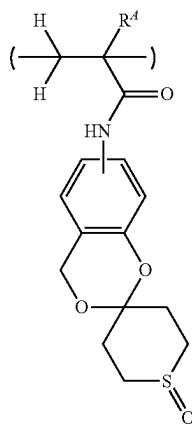
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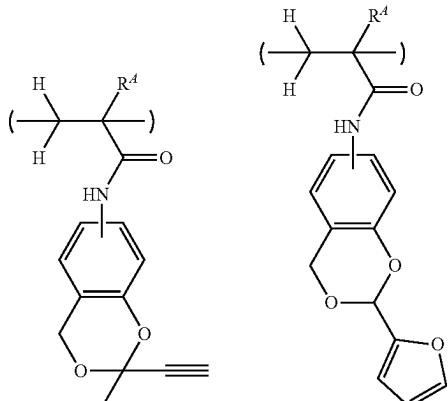
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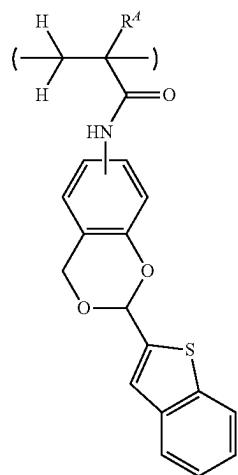
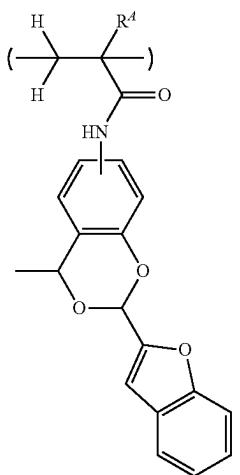
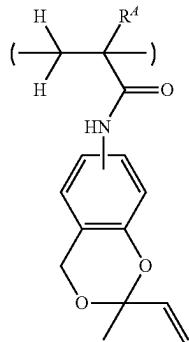
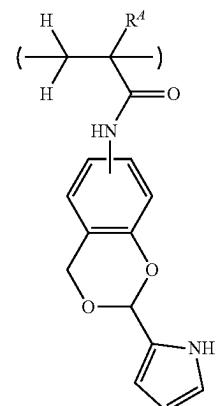
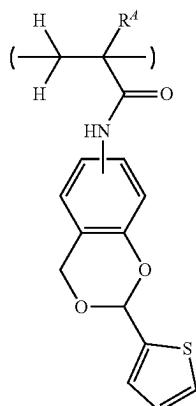
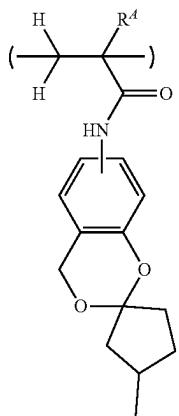
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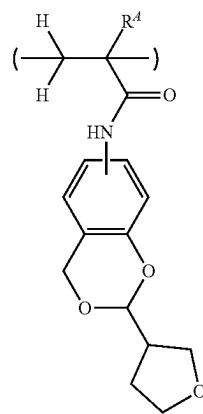
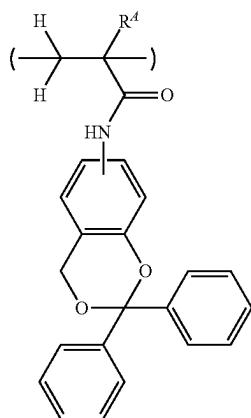
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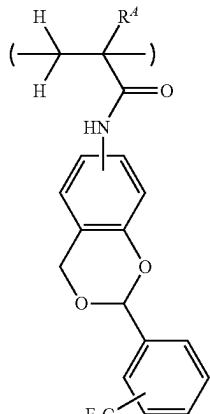
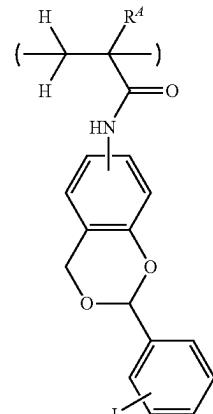
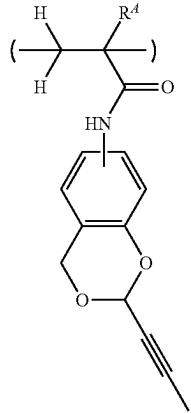
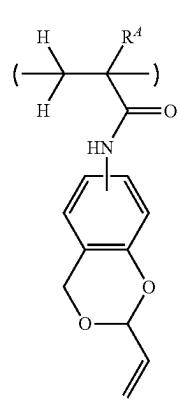
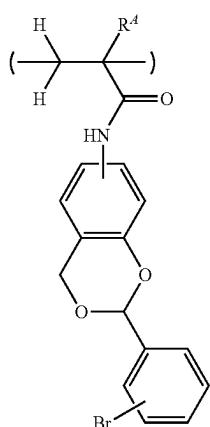
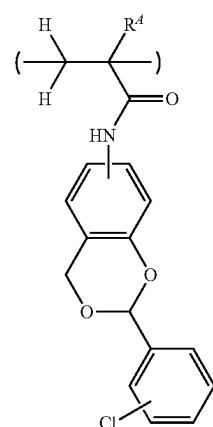
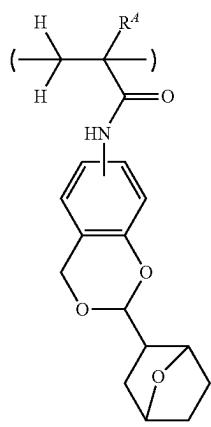
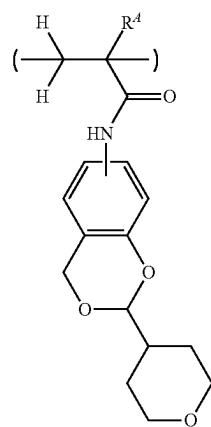
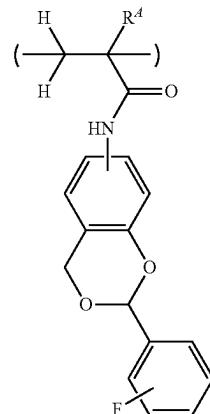
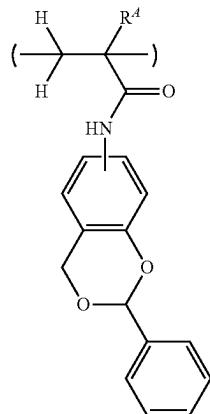
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 (\text{---} \text{H} \text{---}) \text{---} \text{C}(\text{---} \text{R}^A \text{---}) \text{---} \text{C}(=\text{O}) \\
 | \\
 \text{HN} \\
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 \text{---} \text{C}_6\text{H}_3\text{O} \text{---} \\
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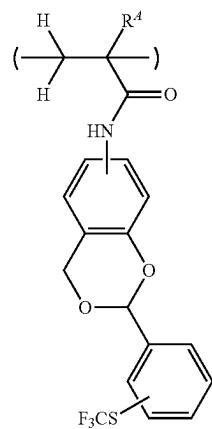
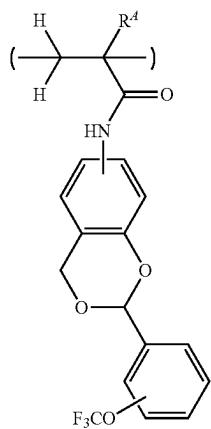
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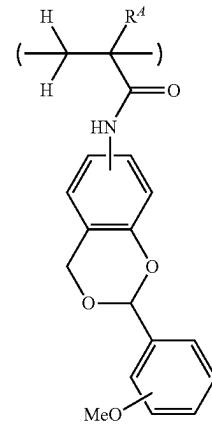
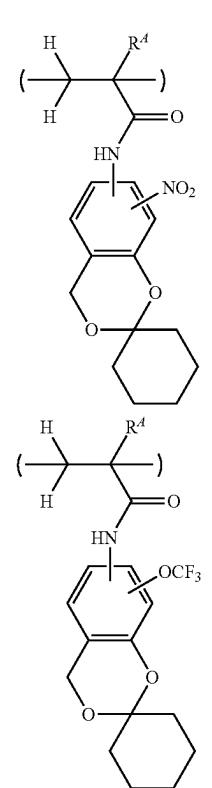
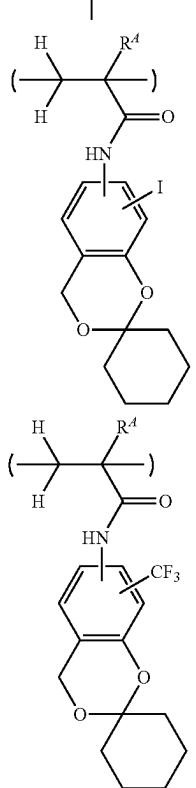
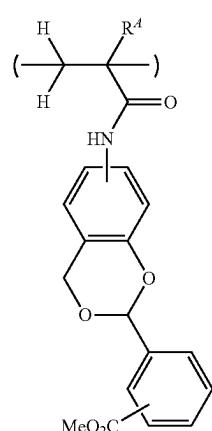
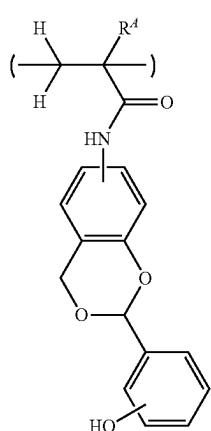
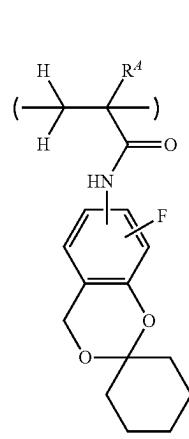
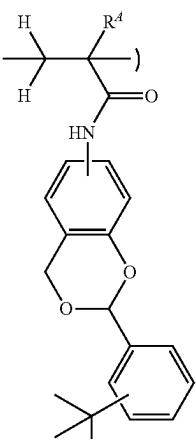
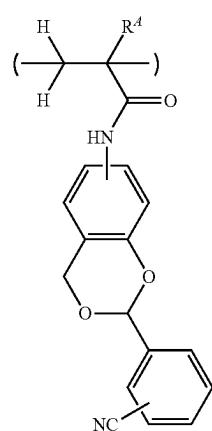
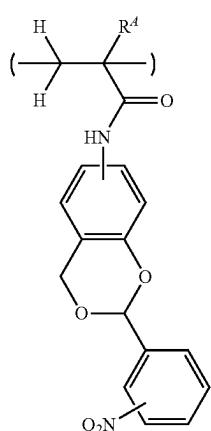
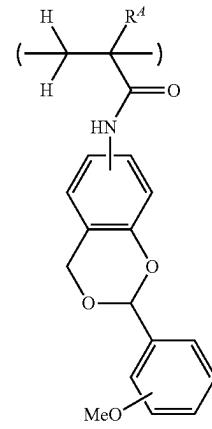
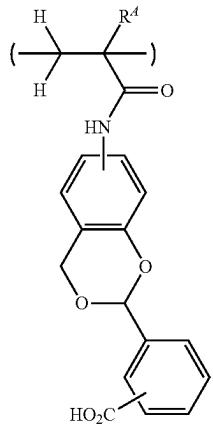
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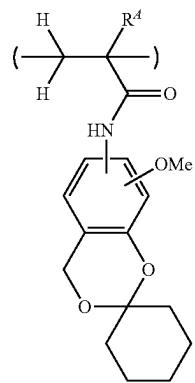
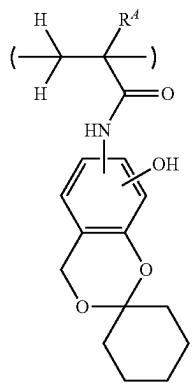
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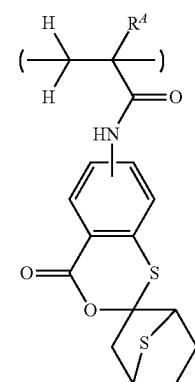
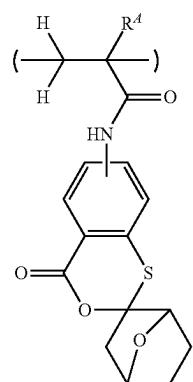
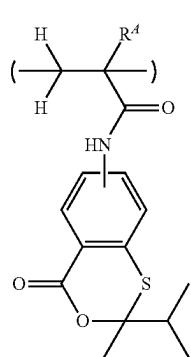
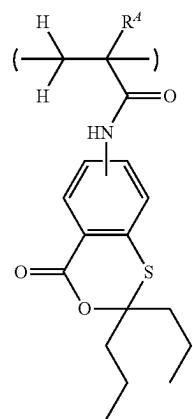
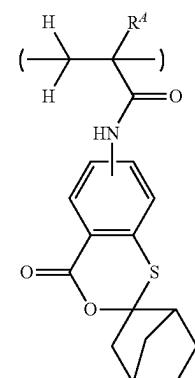
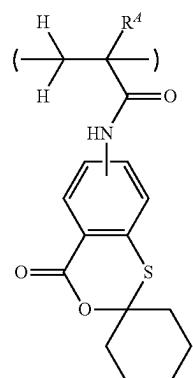
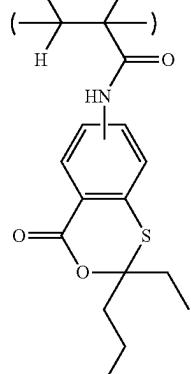
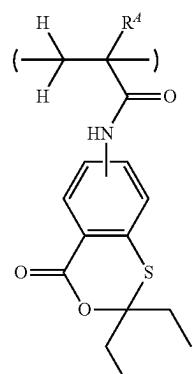
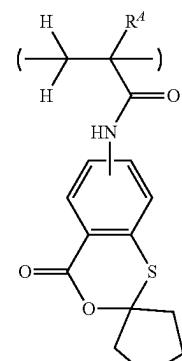
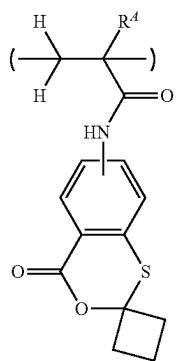
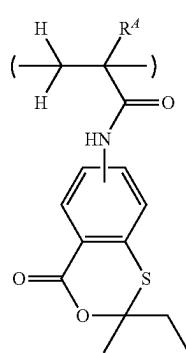
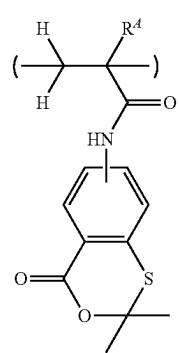
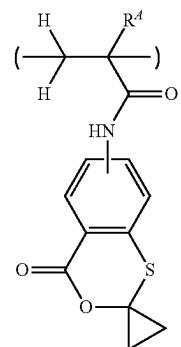
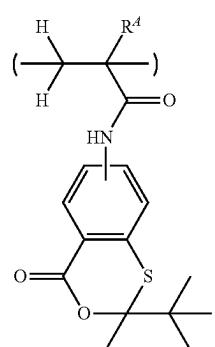
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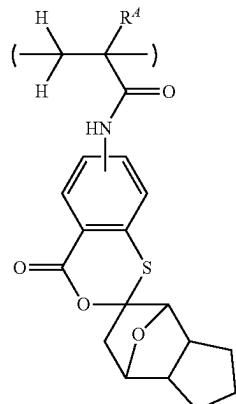
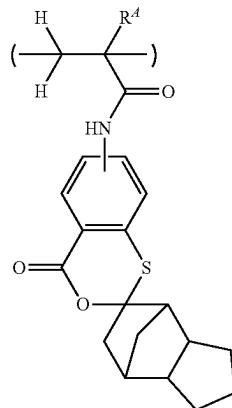
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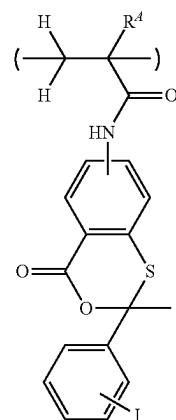
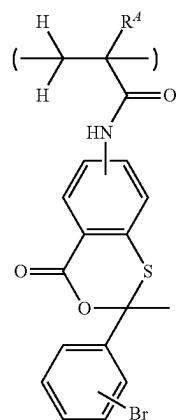
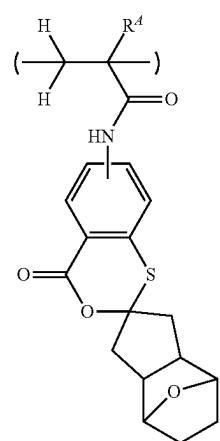
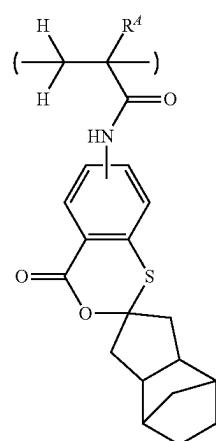
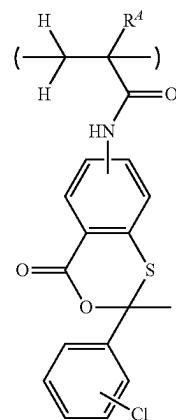
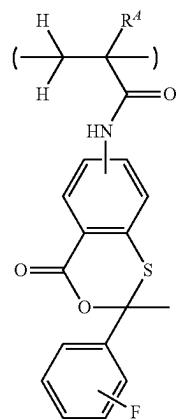
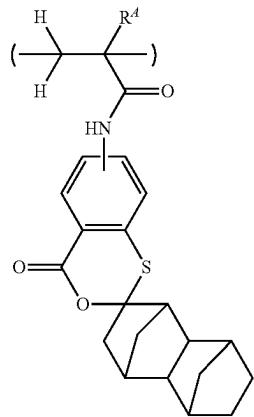
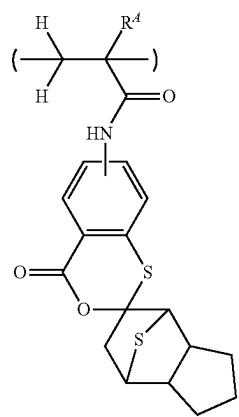
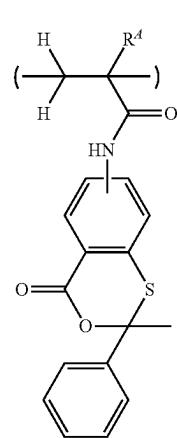
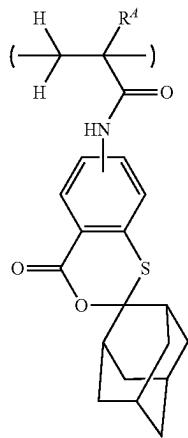
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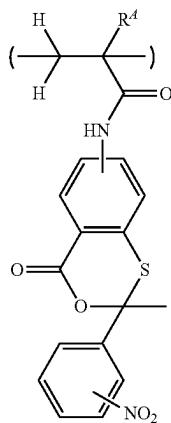
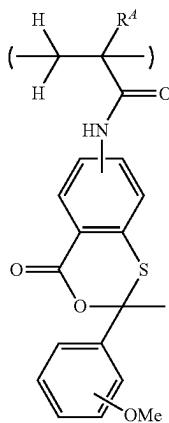
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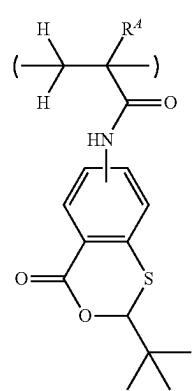
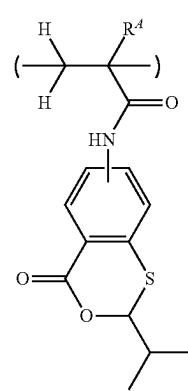
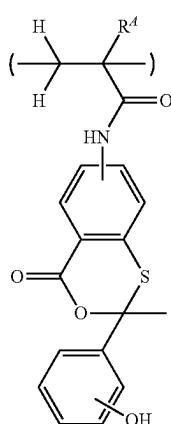
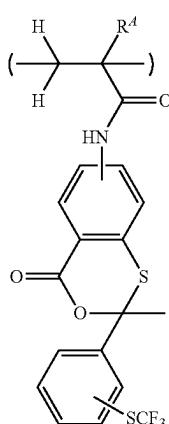
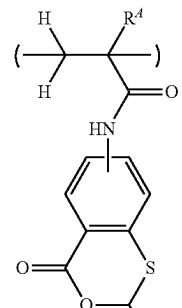
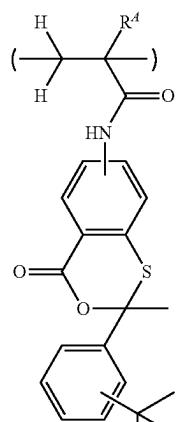
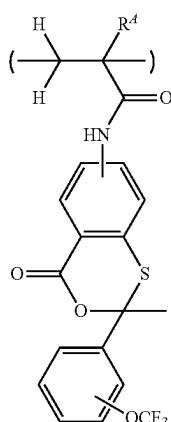
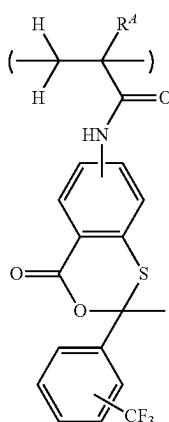
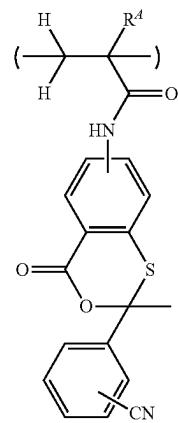
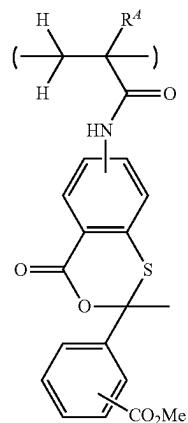
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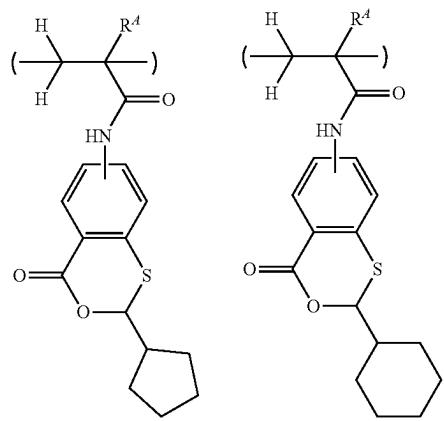
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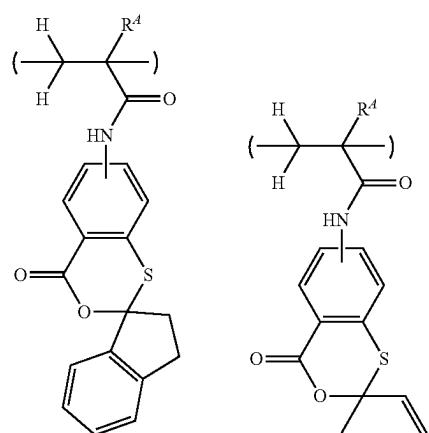
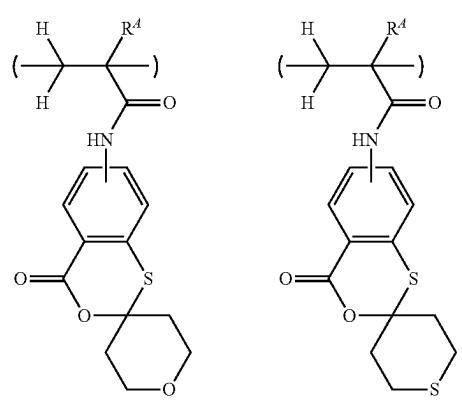
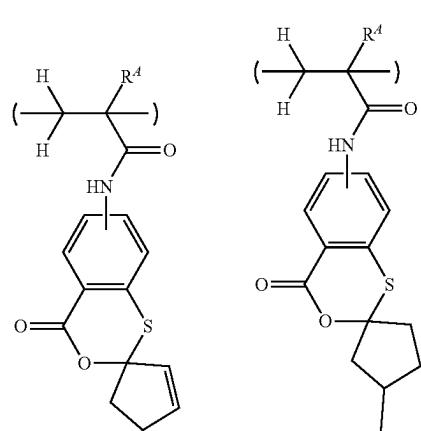
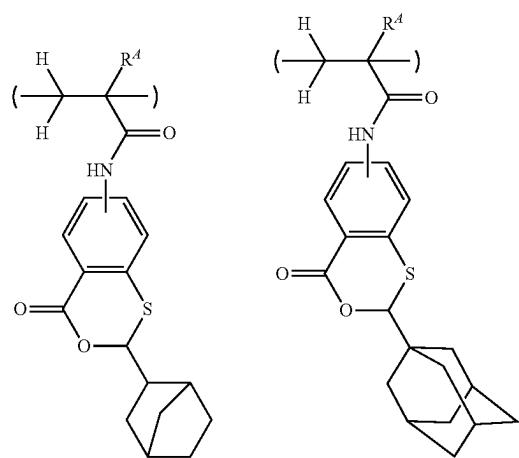
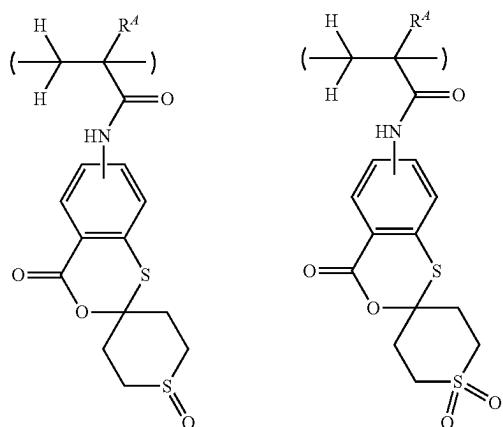
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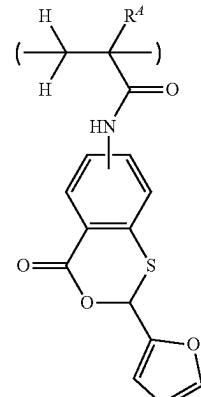
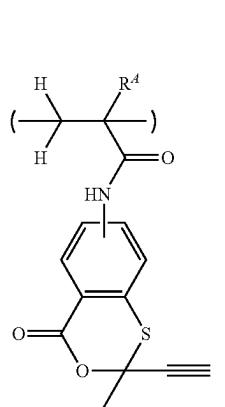
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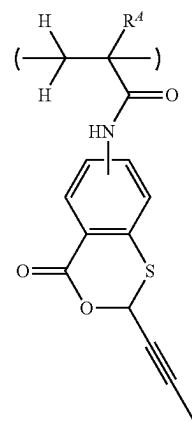
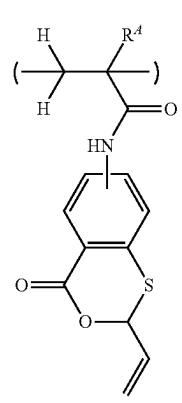
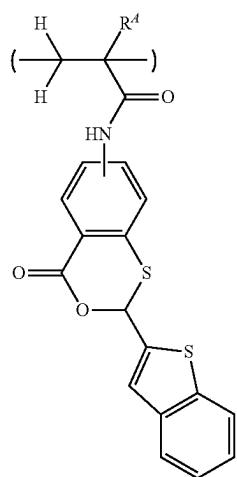
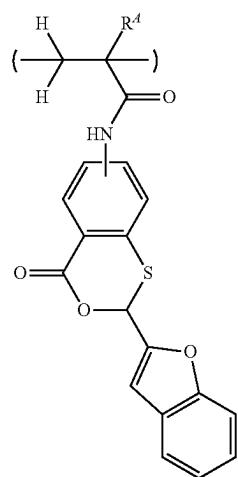
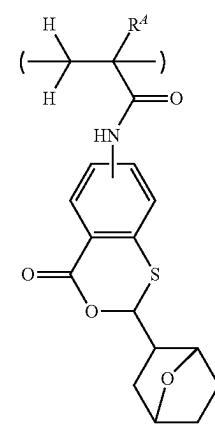
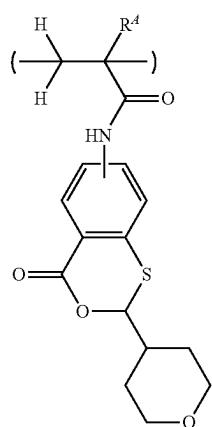
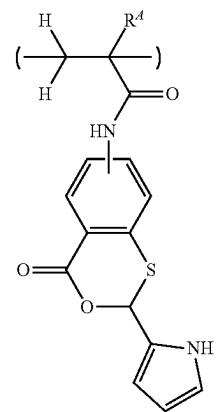
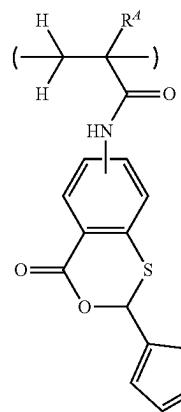
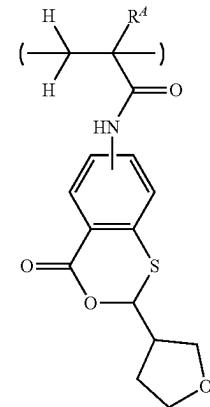
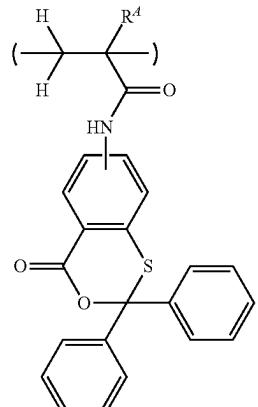
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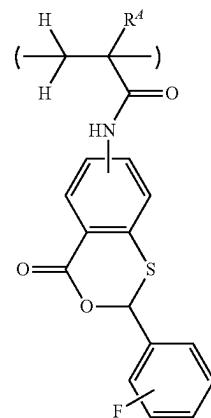
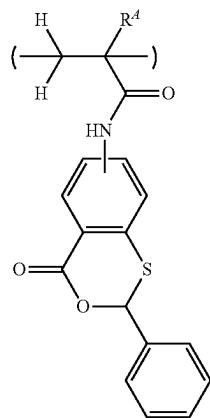
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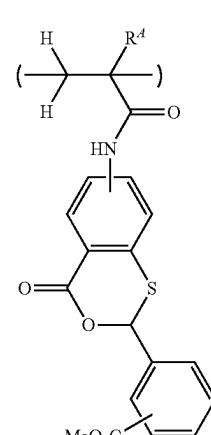
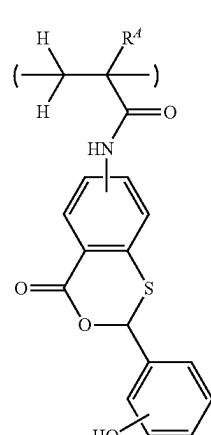
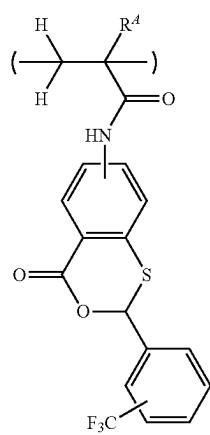
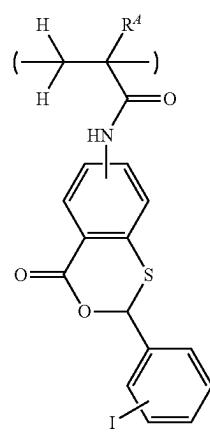
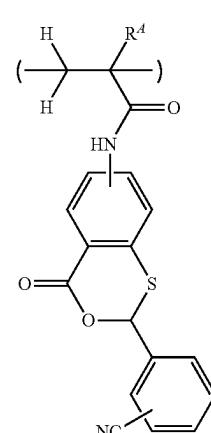
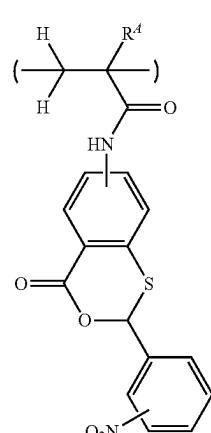
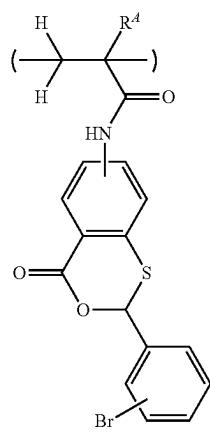
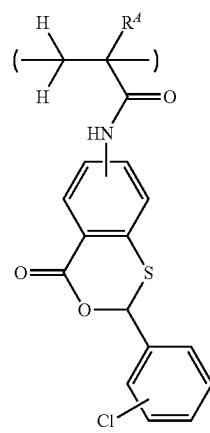
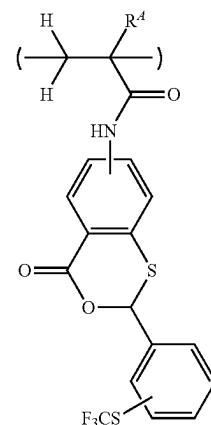
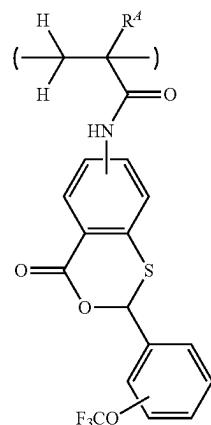
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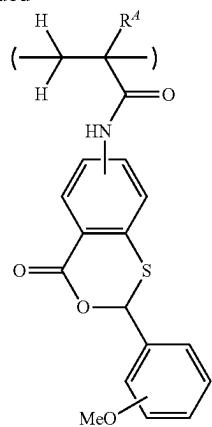
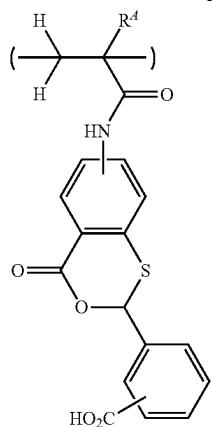
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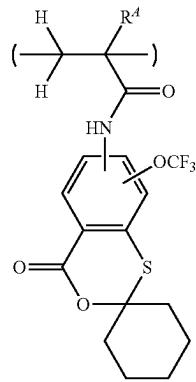
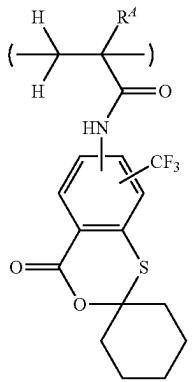
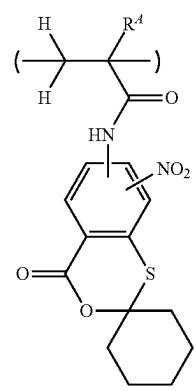
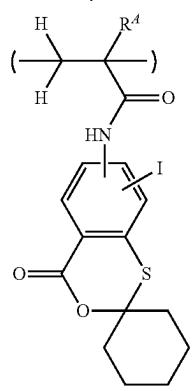
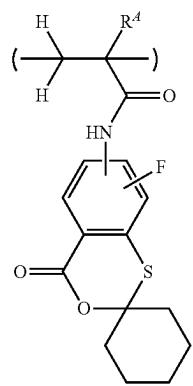
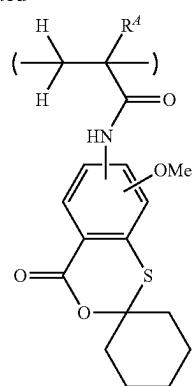
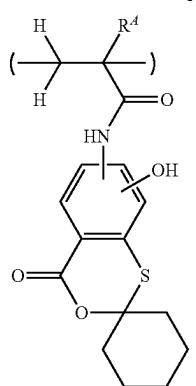
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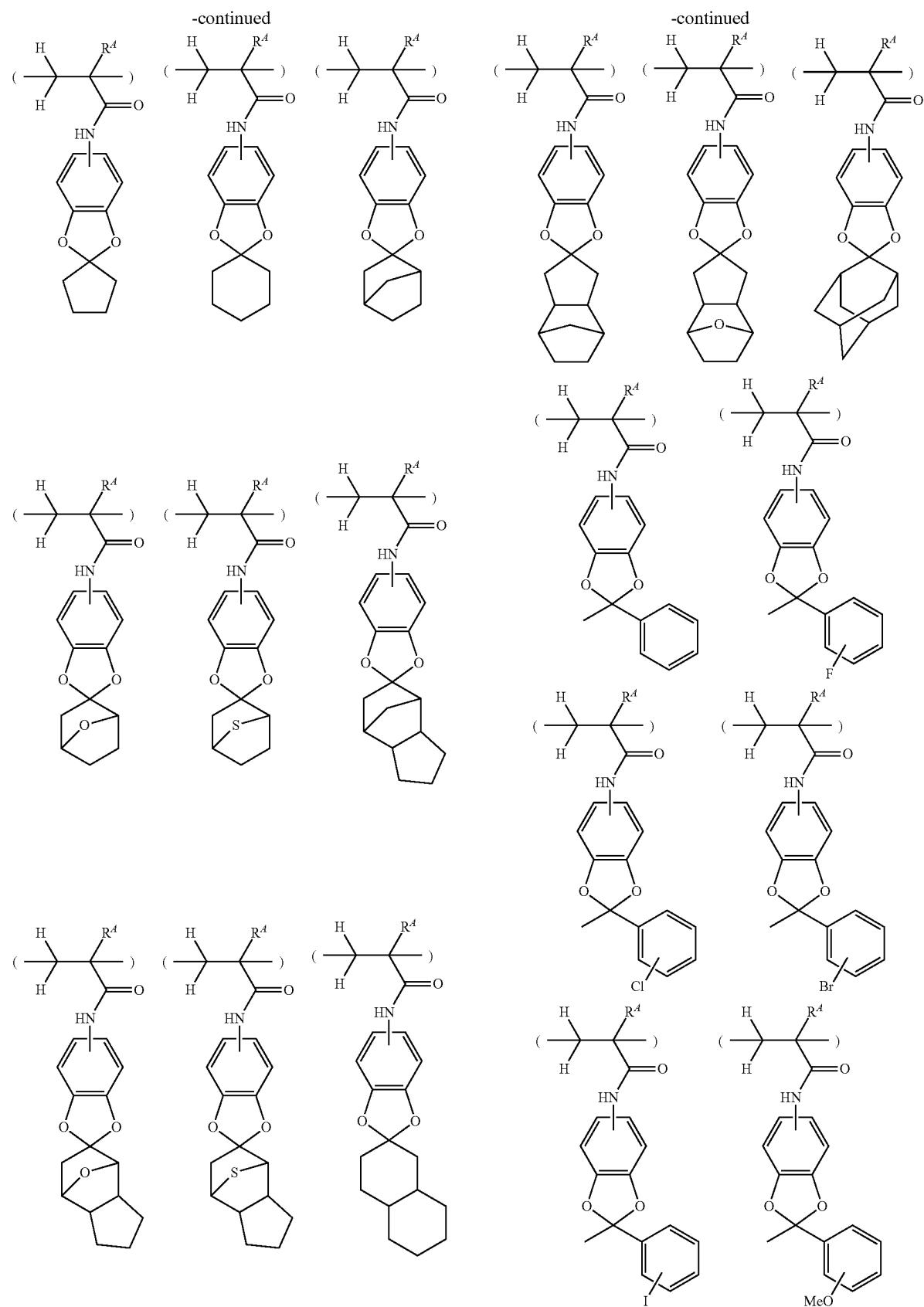


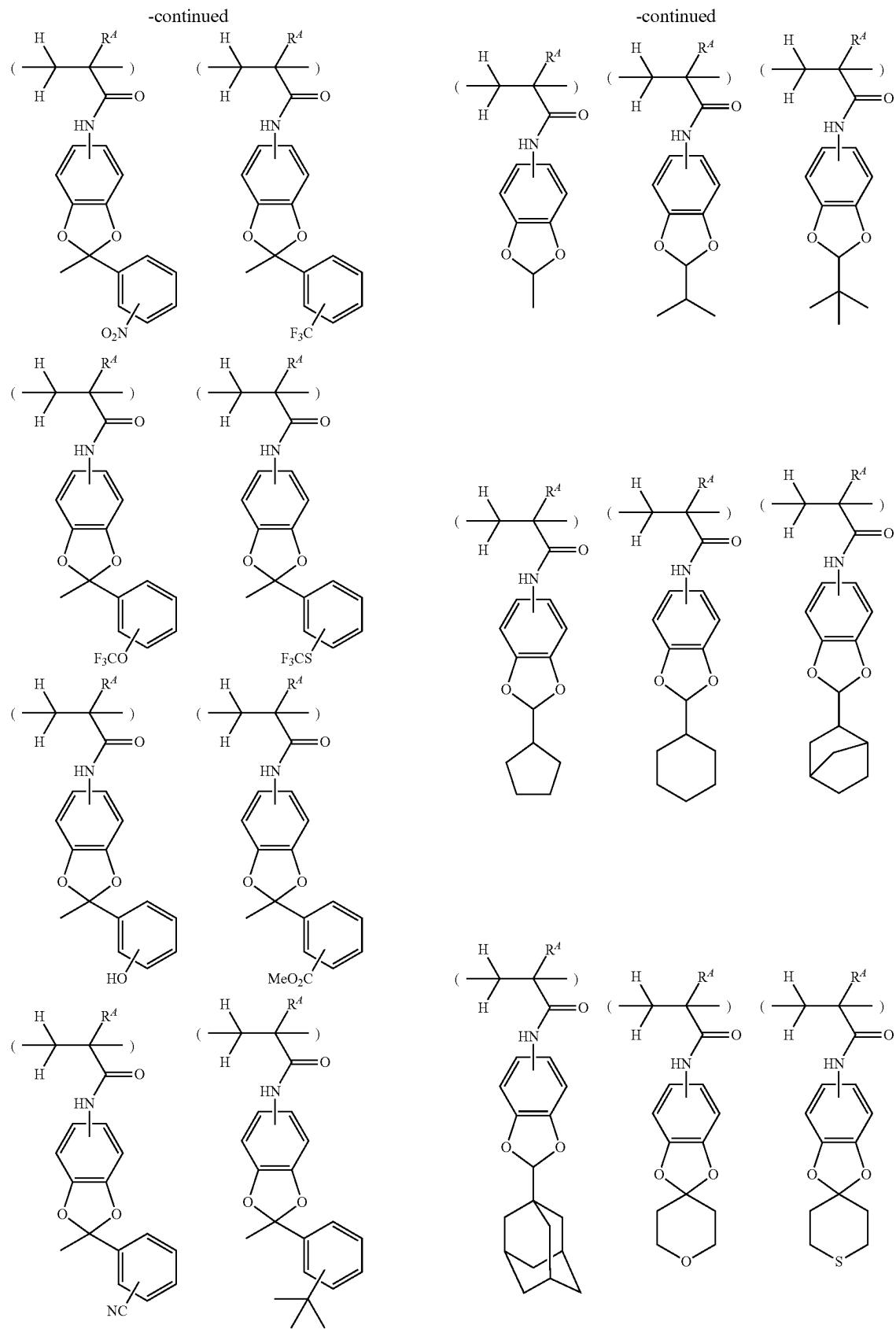
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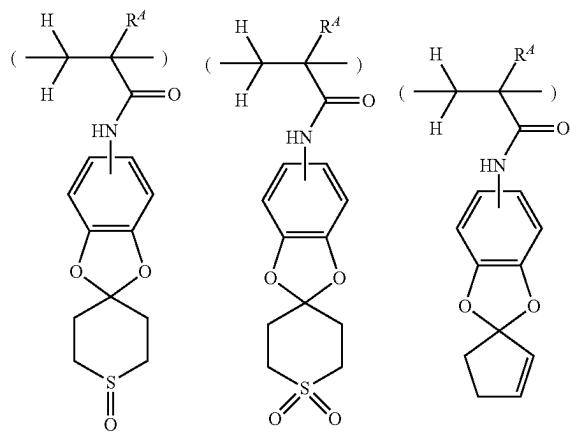
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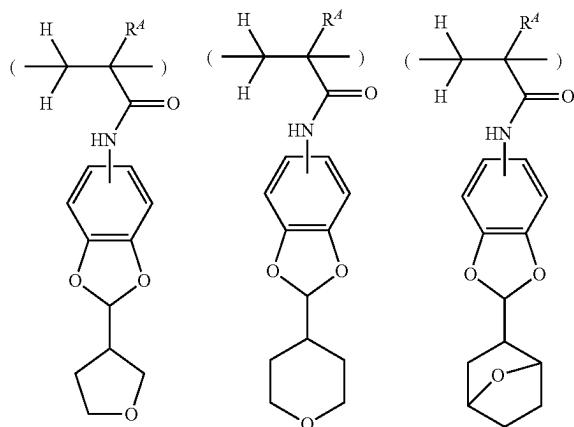
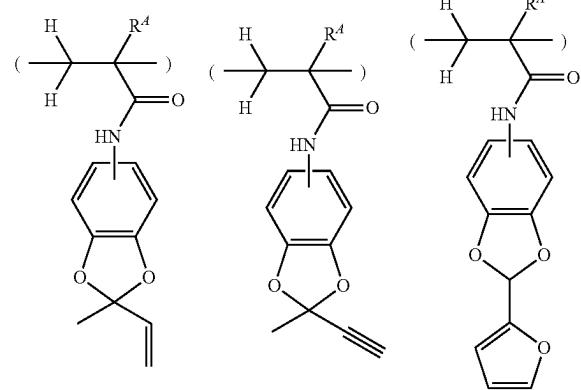
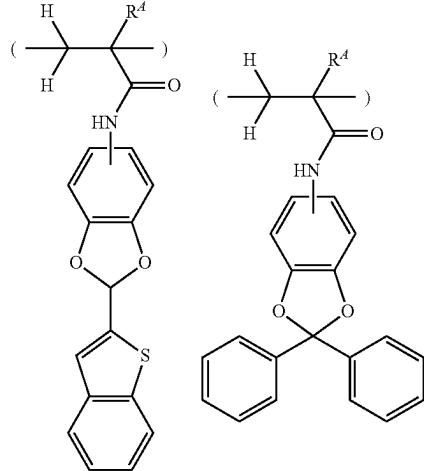
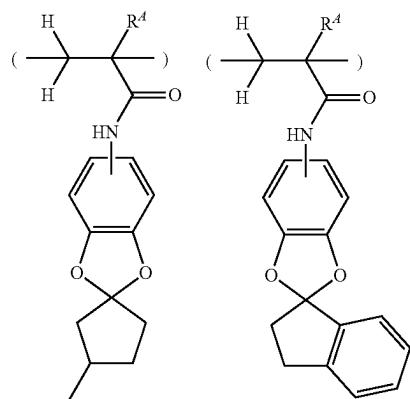
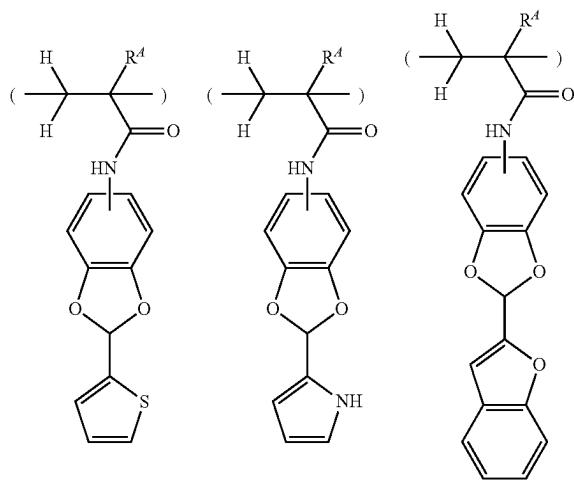


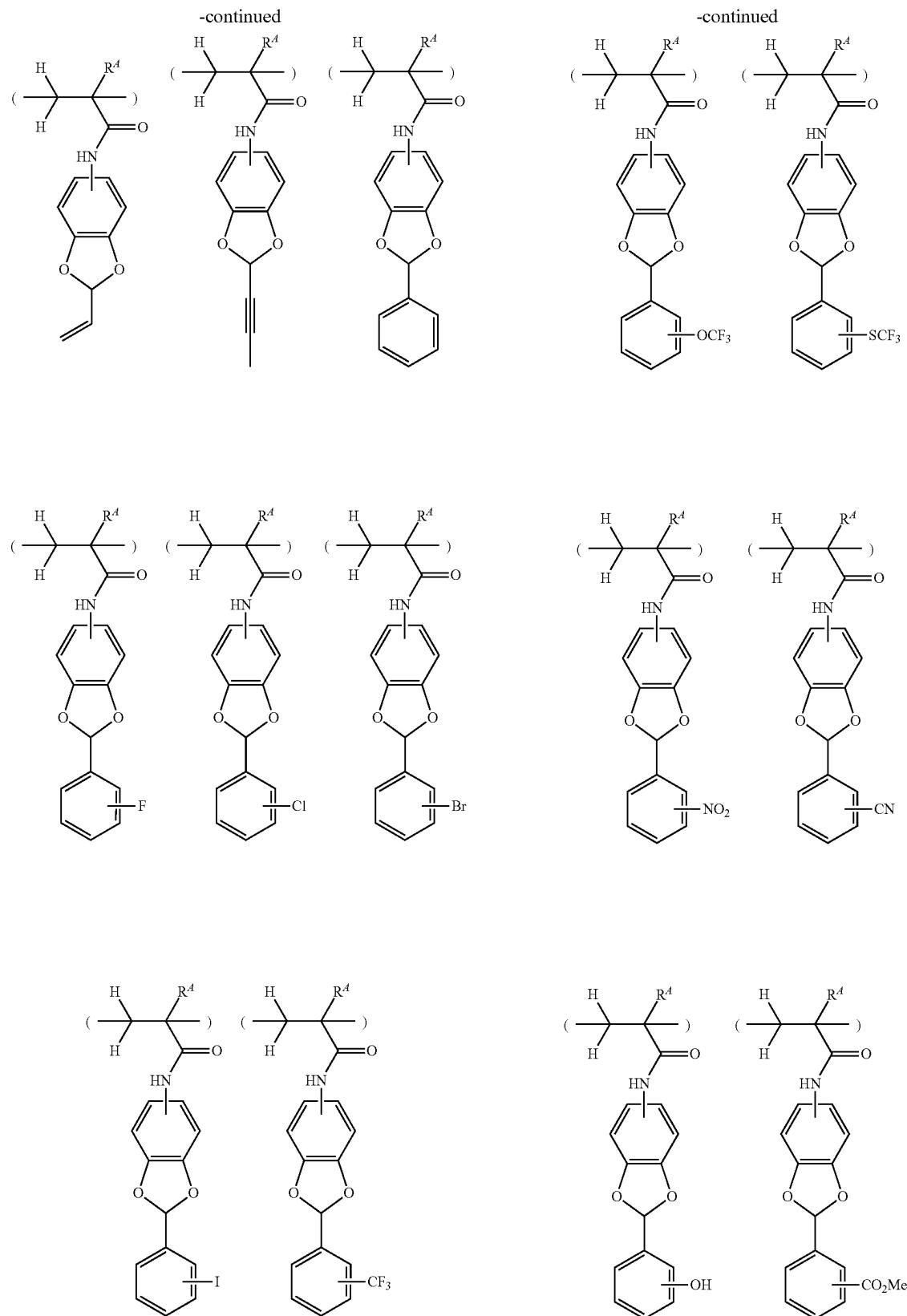


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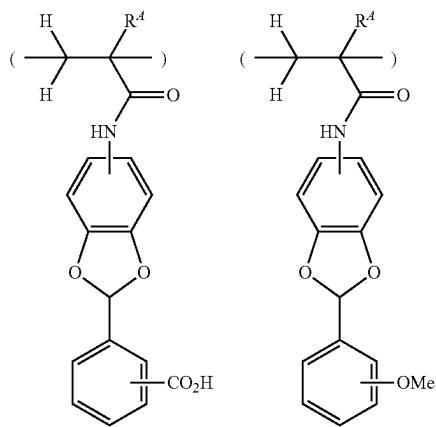


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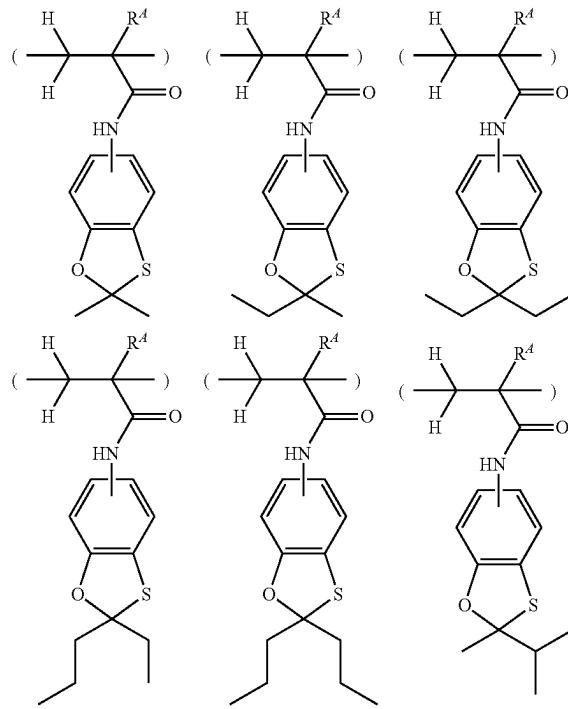
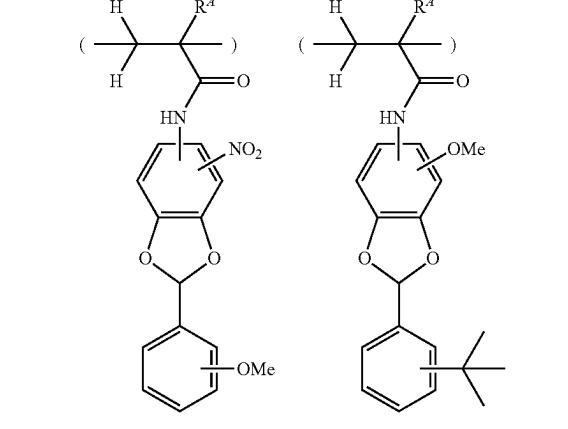
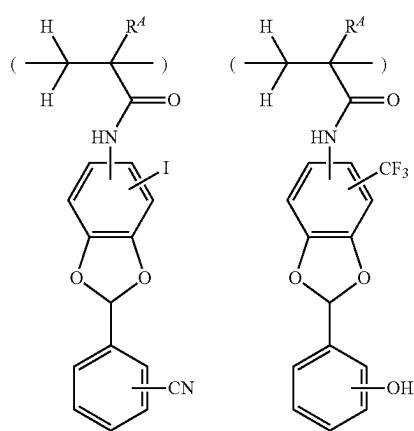
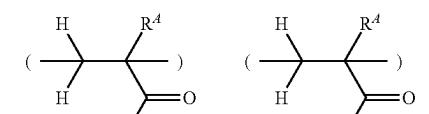
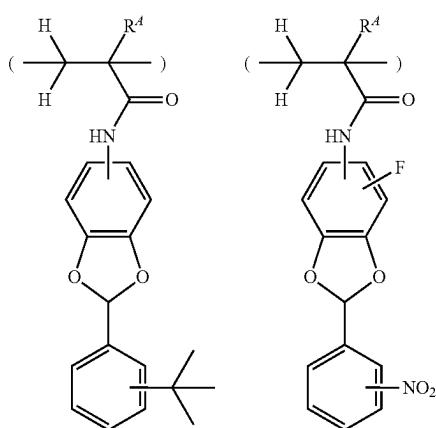
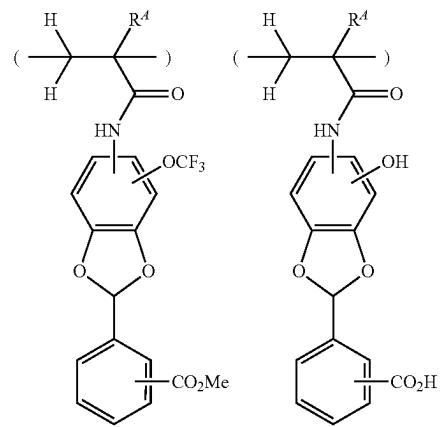


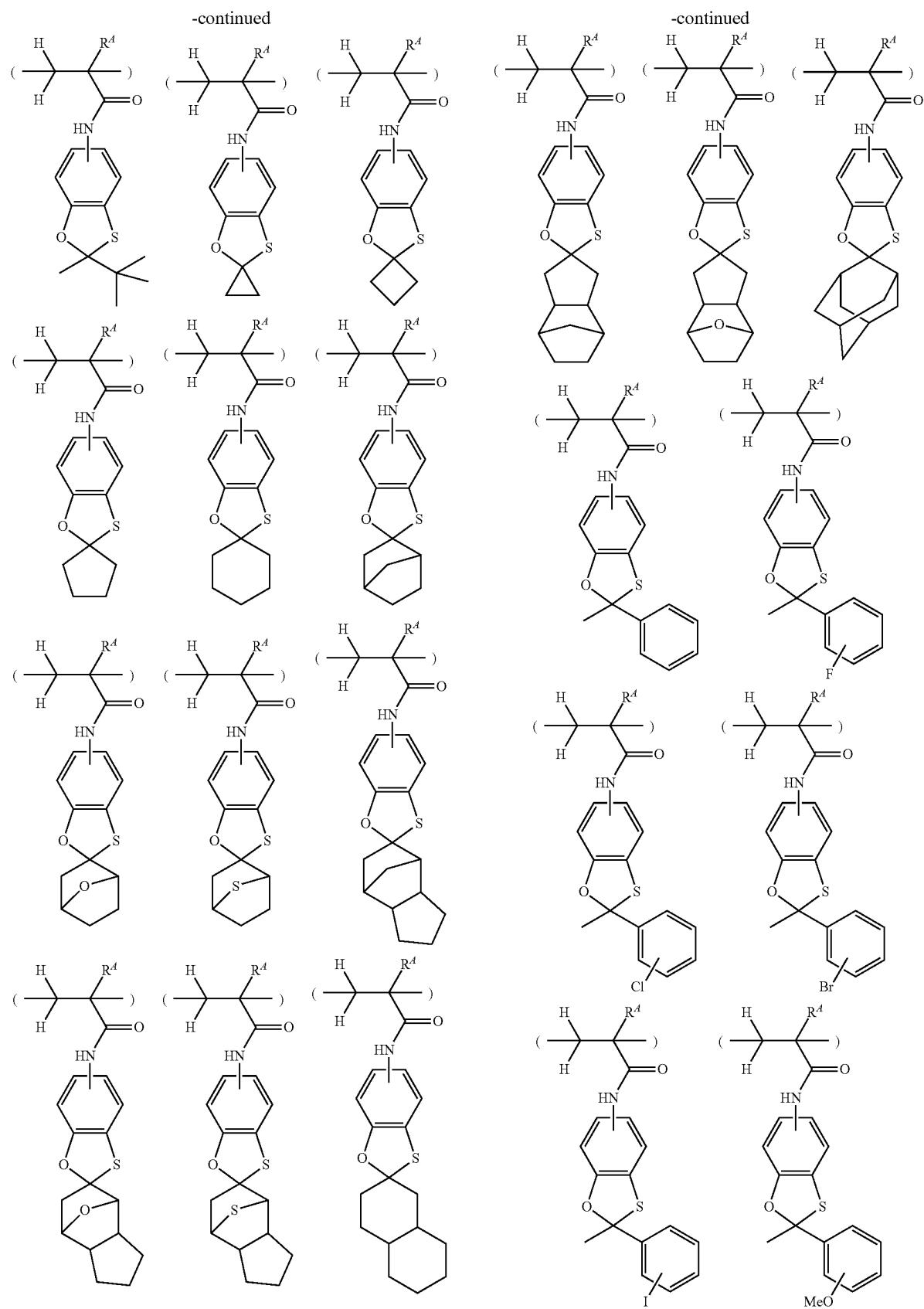


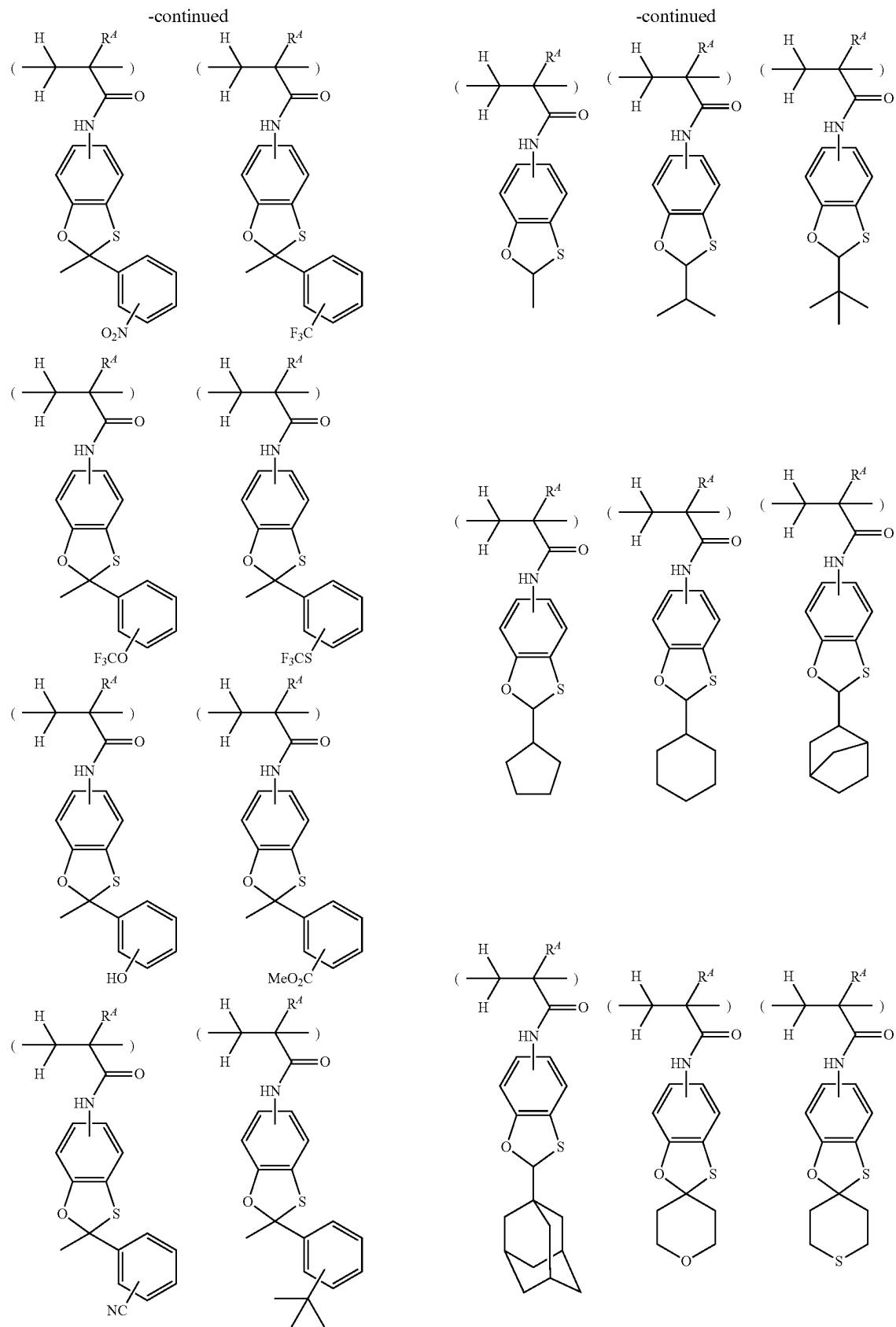
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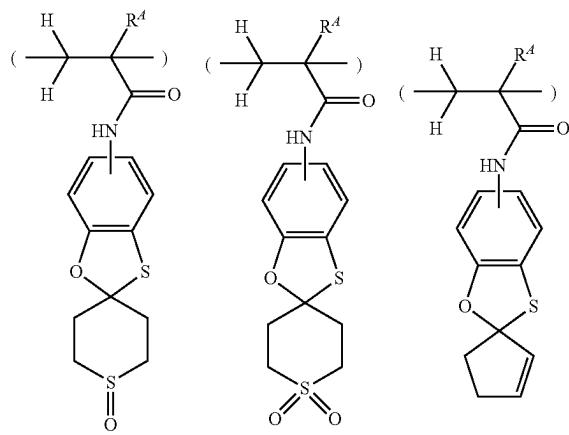
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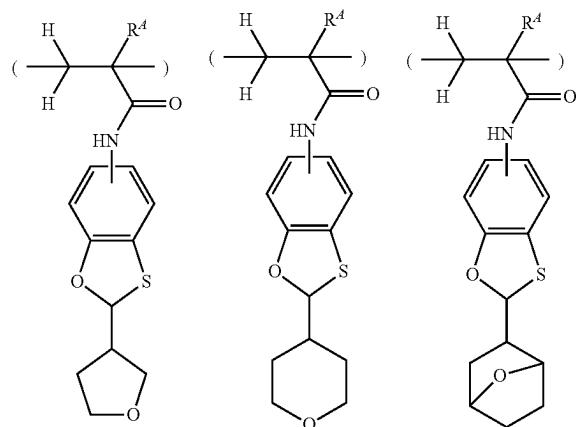
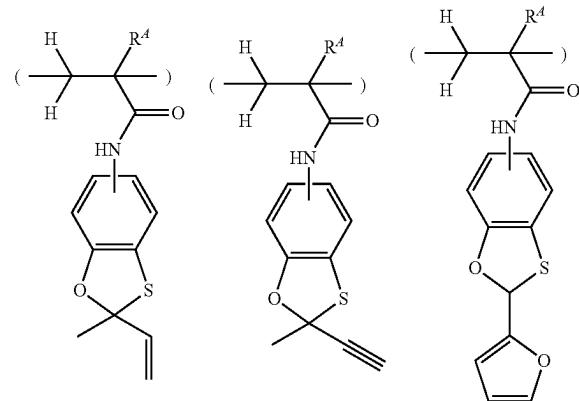
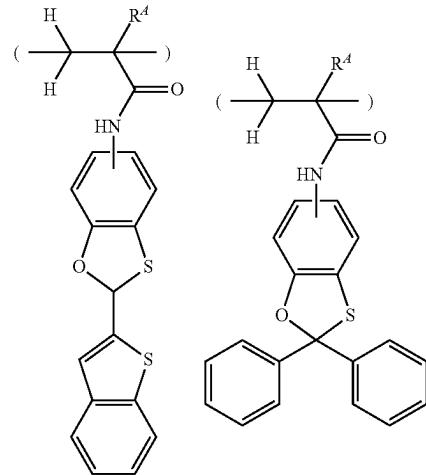
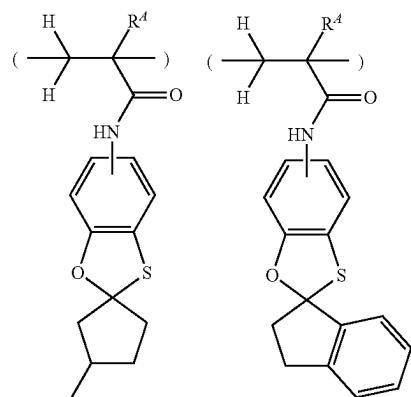
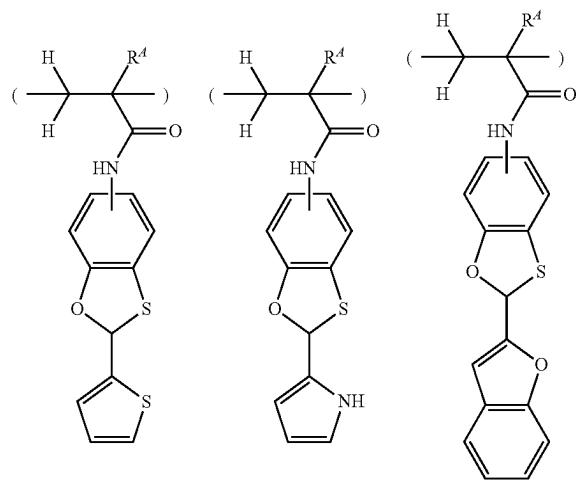


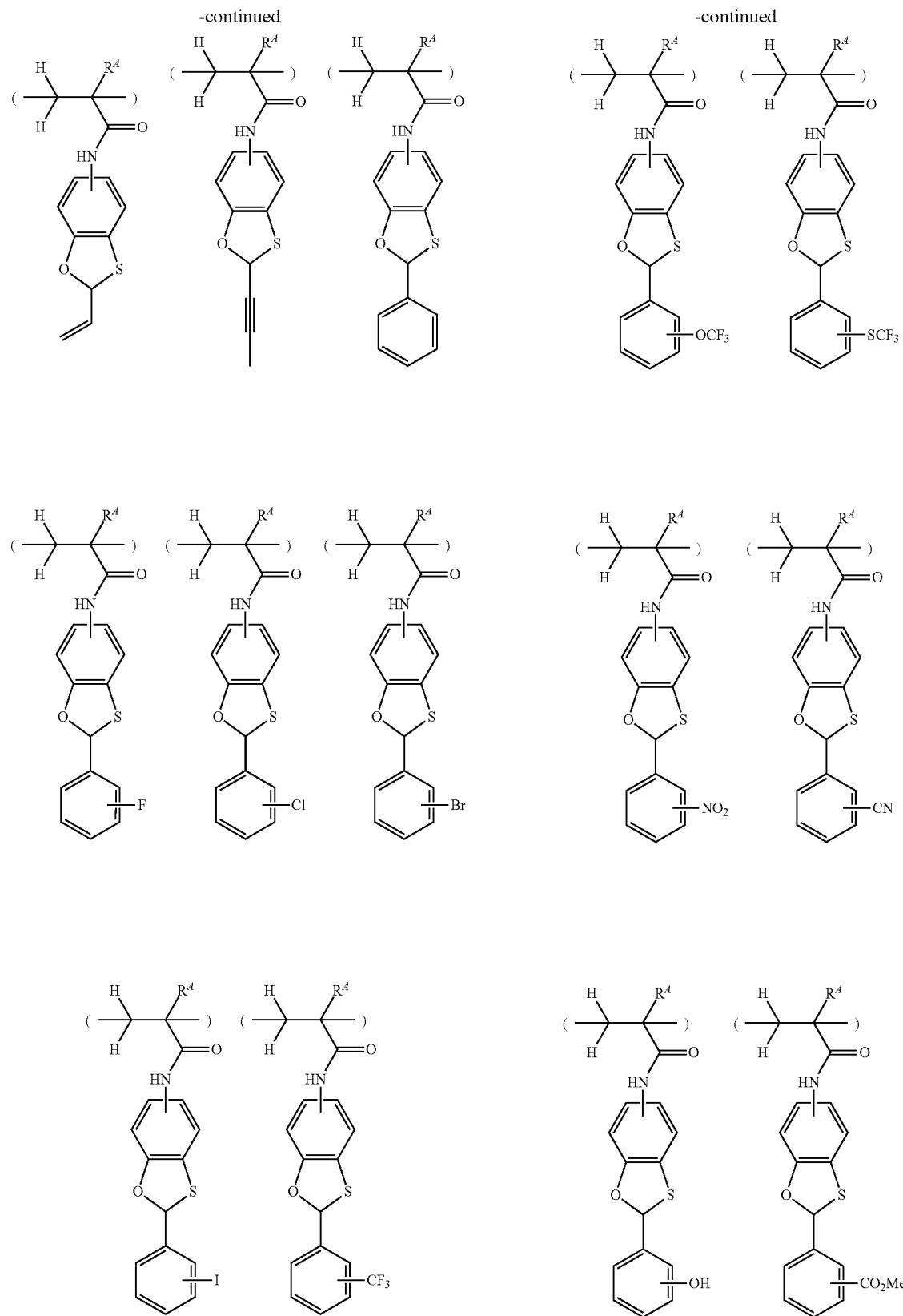


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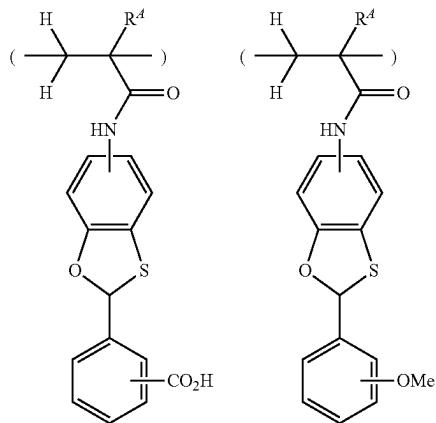


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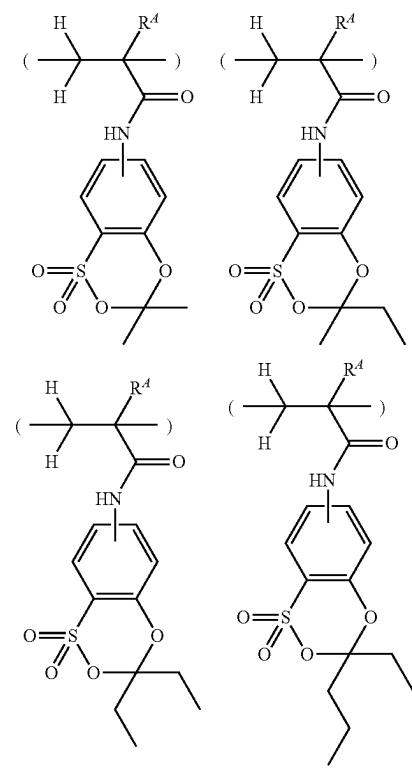
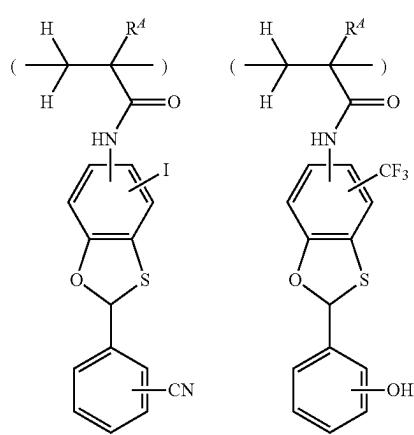
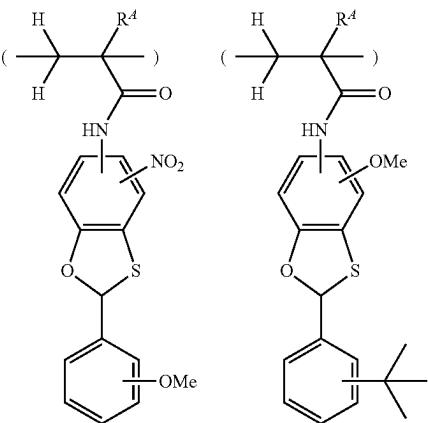
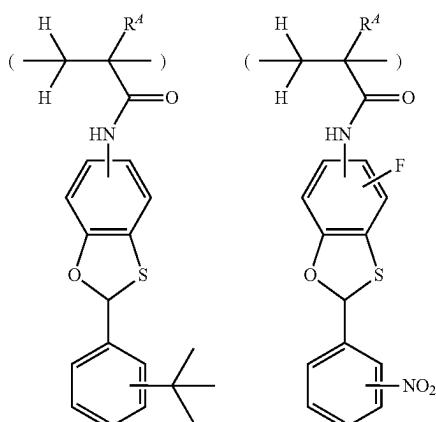
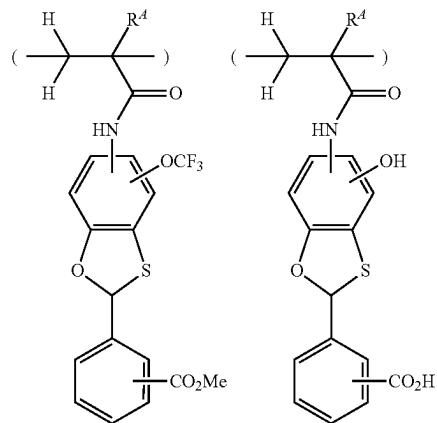




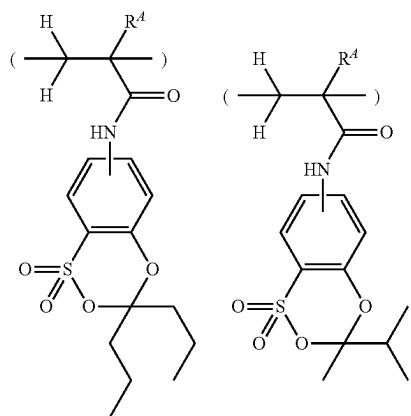
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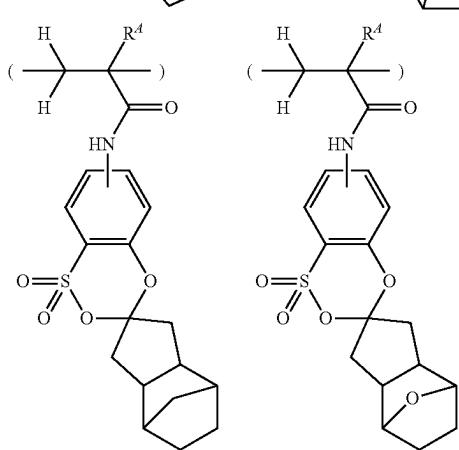
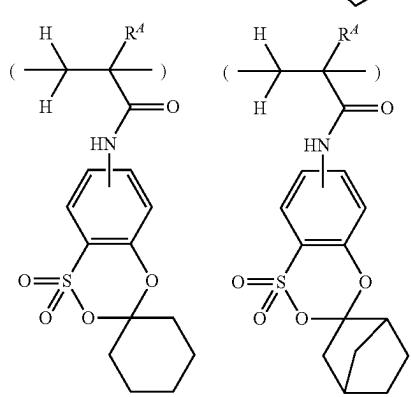
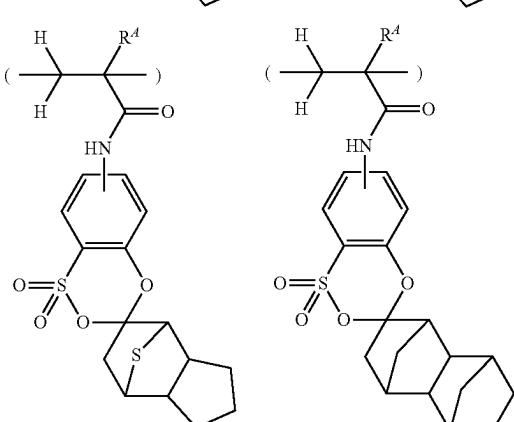
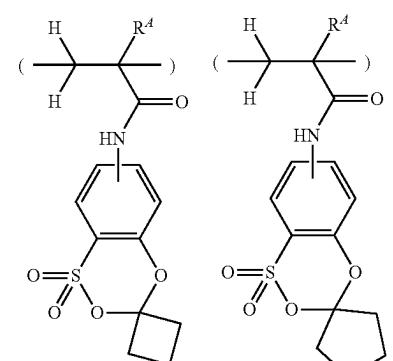
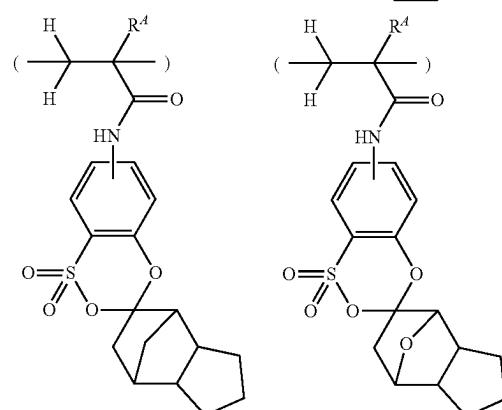
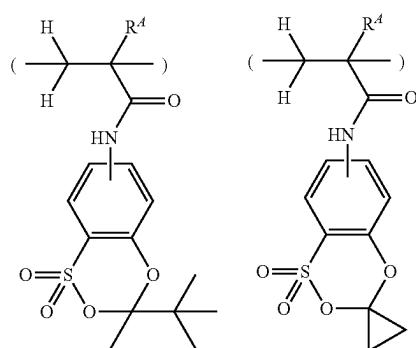
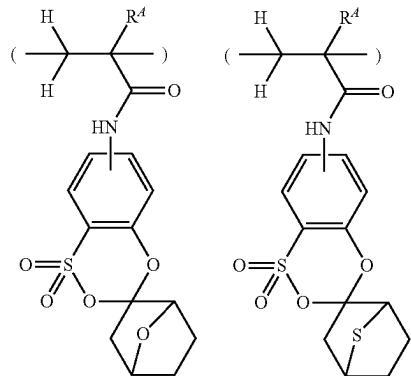
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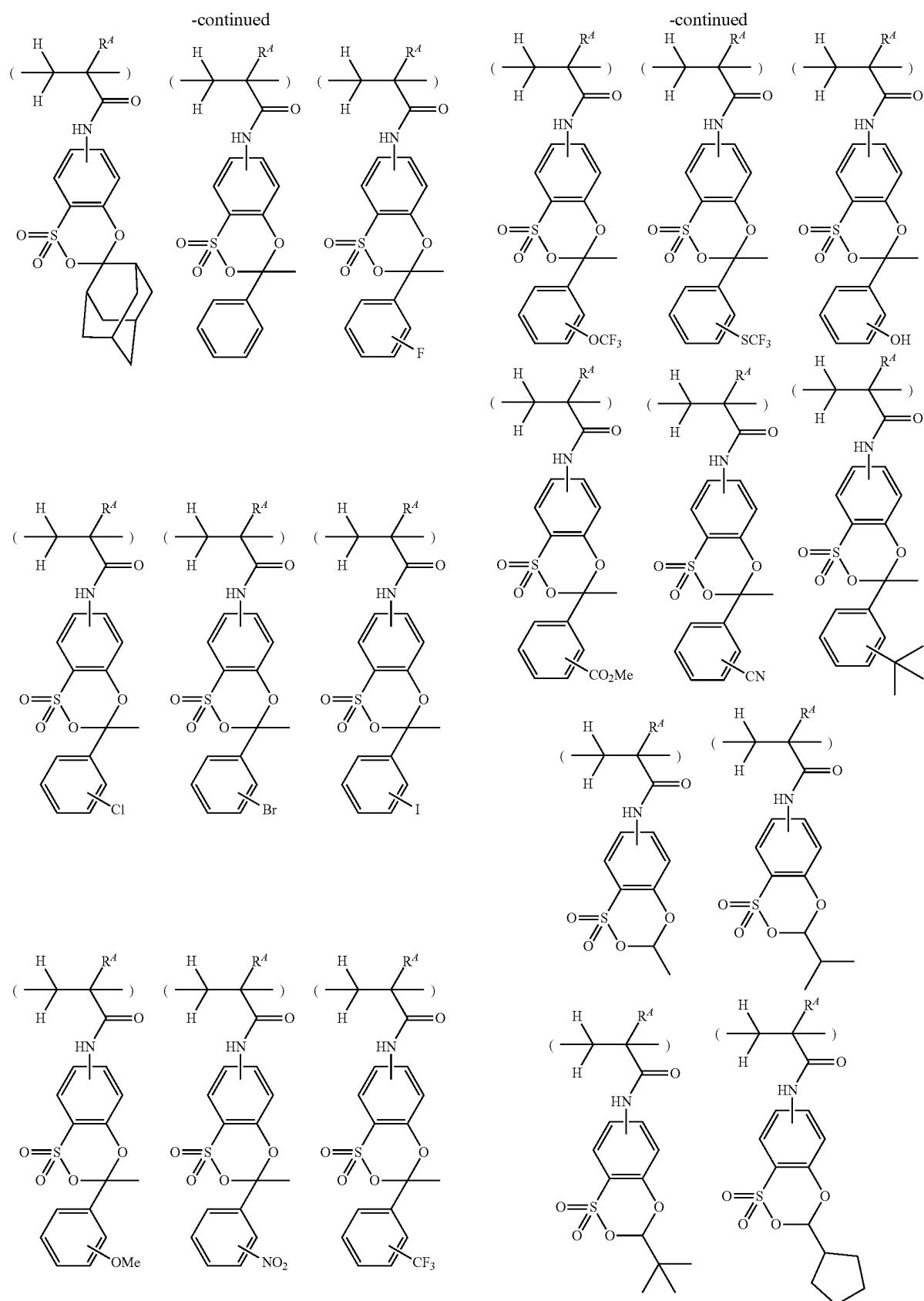


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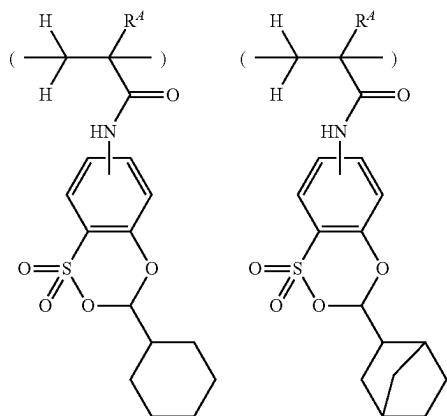


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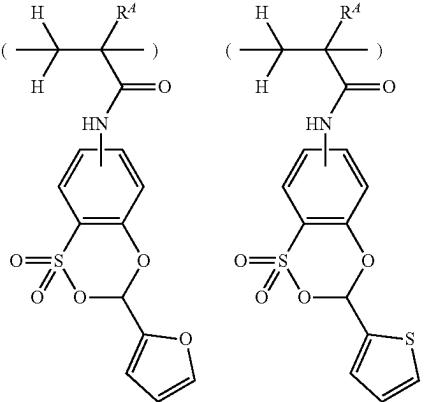
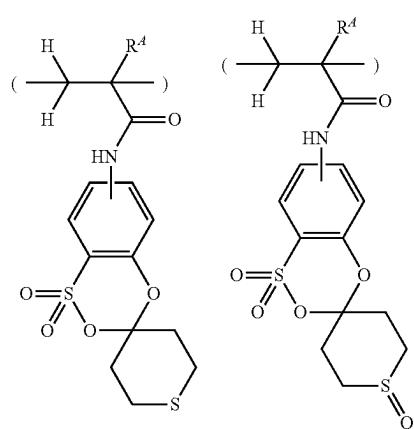
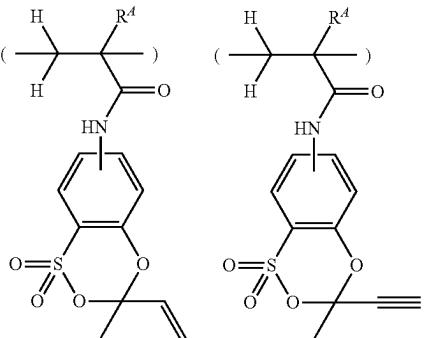
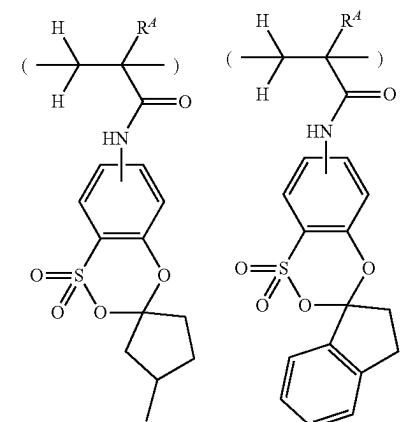
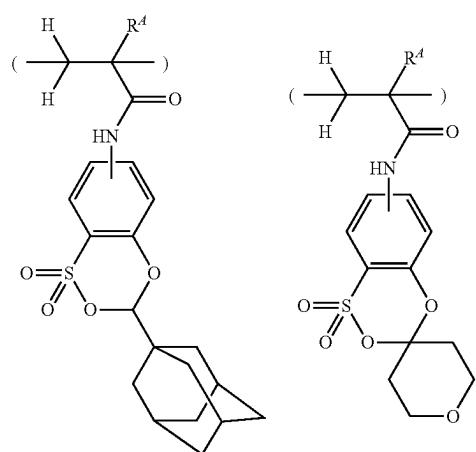
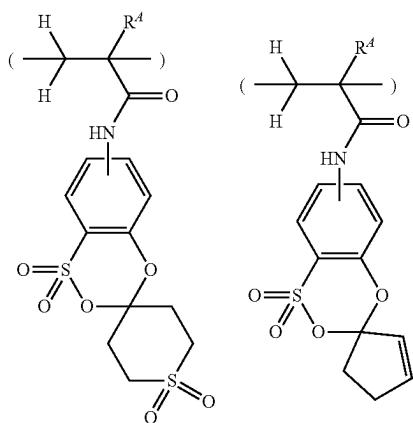




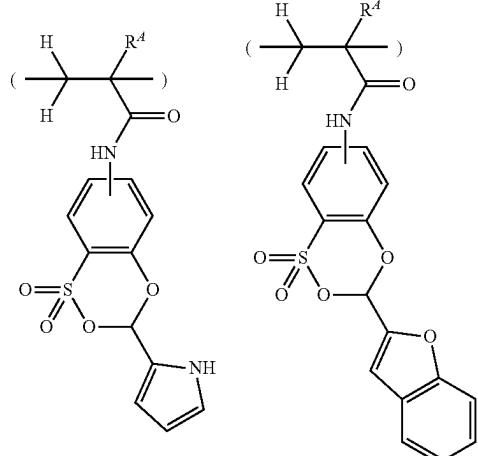
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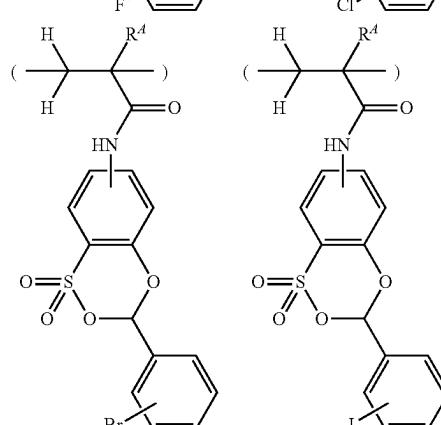
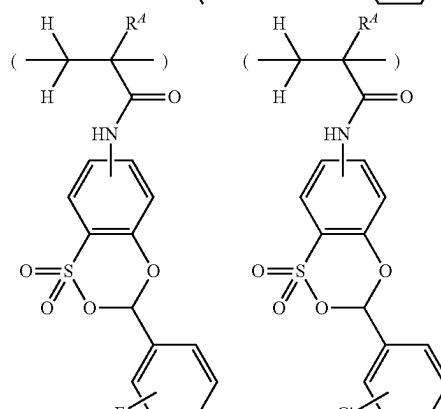
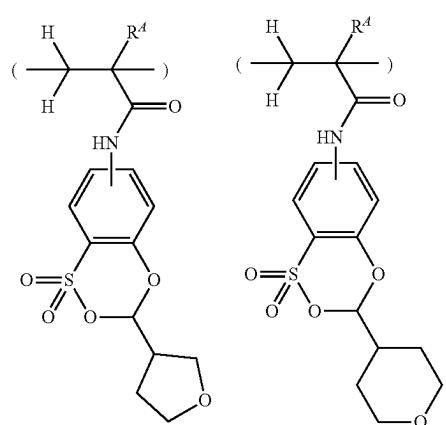
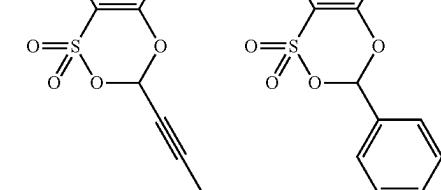
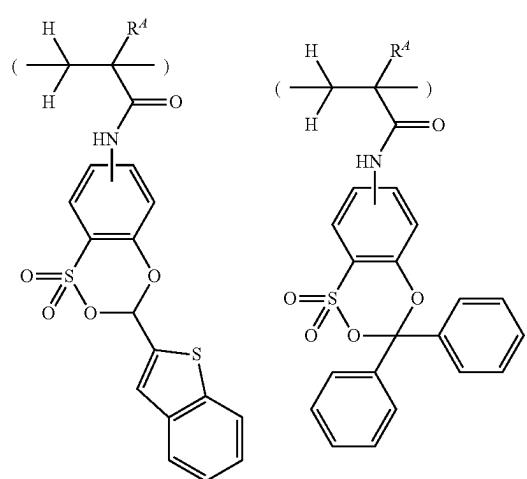
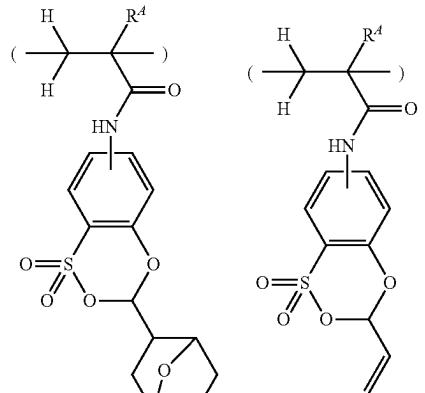
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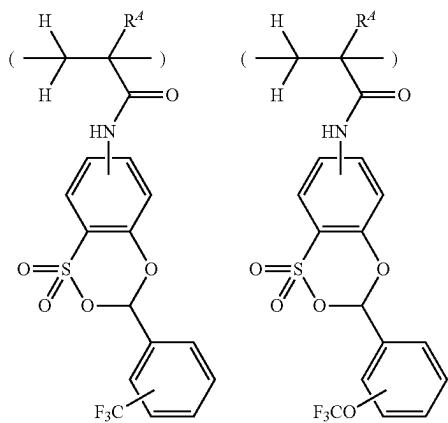
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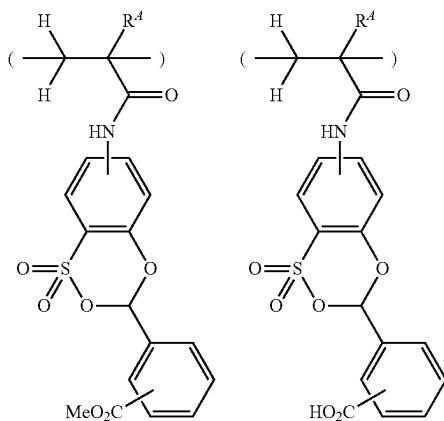
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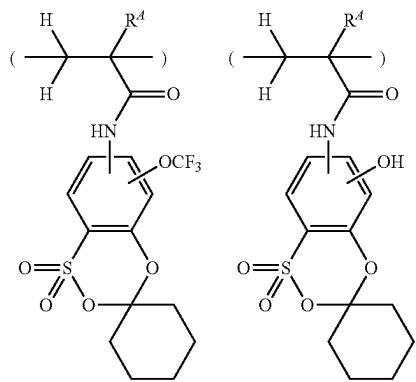


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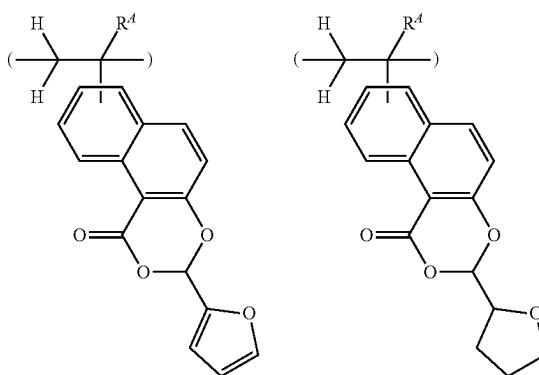
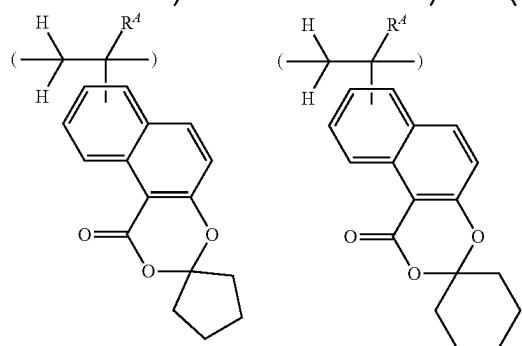
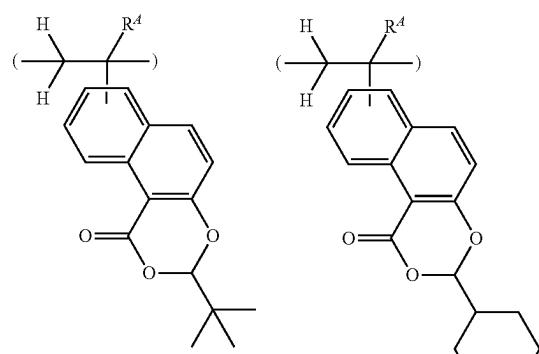
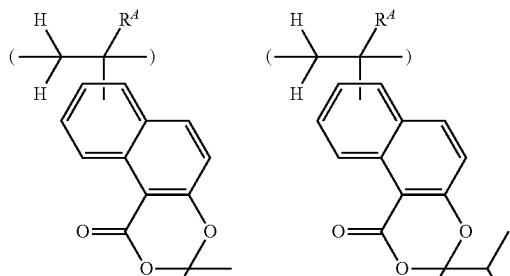
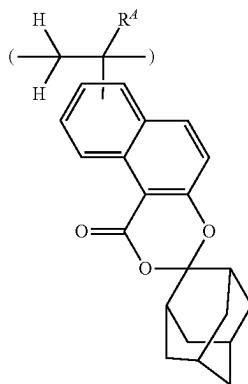
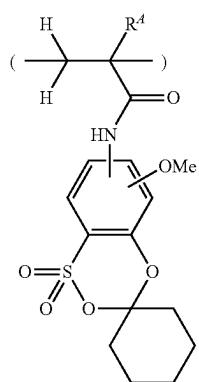
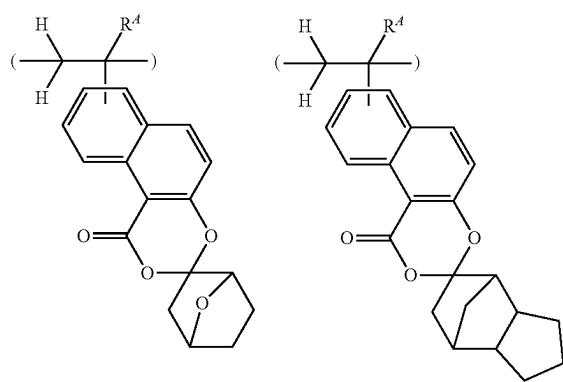


The figure displays two chemical structures side-by-side. Both structures feature a central methoxyphenyl group (a benzene ring with an -OCH₃ group). In the left structure, the para position of this ring is substituted with a 4-methoxyphenyl group (a benzene ring with an -OCH₃ group at the para position). The meta position of the central ring is substituted with a methoxymethyl group (-CH₂OCH₃). This group is further substituted with a sulfonyl group (-OSO₂CH₃). In the right structure, the para position of the central ring is substituted with a 4-tert-butylphenyl group (a benzene ring with a tert-butyl group at the para position).

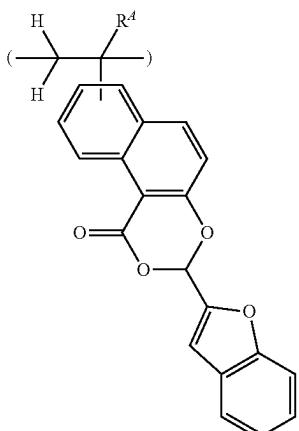
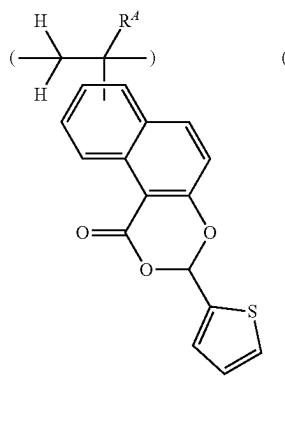
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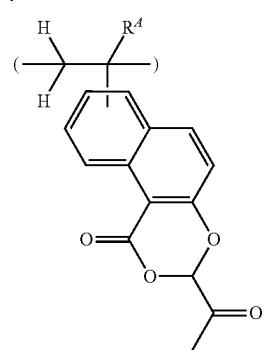
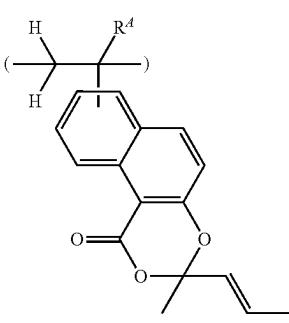
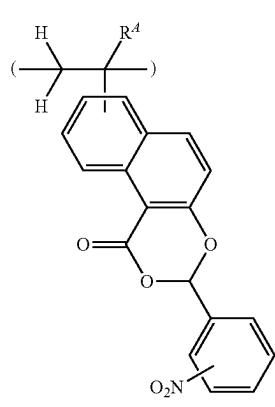
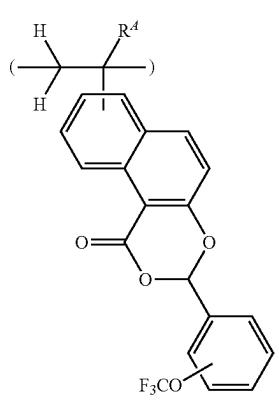
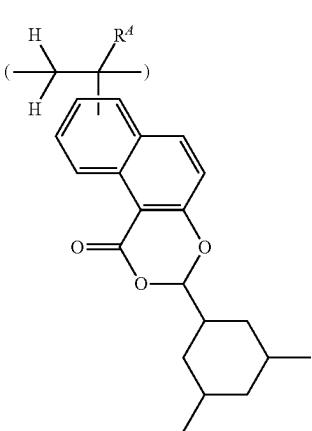
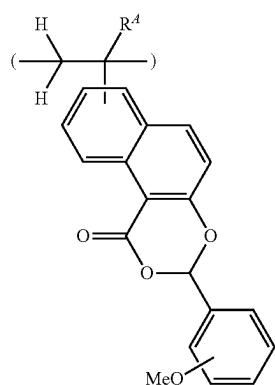
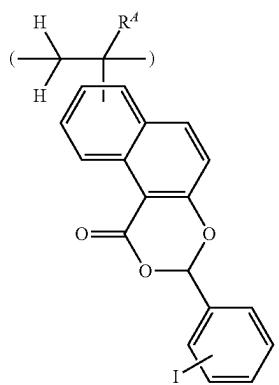
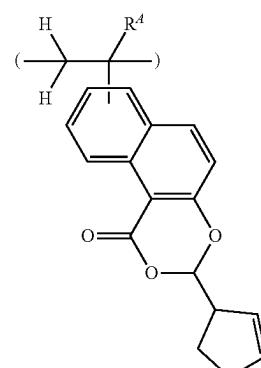
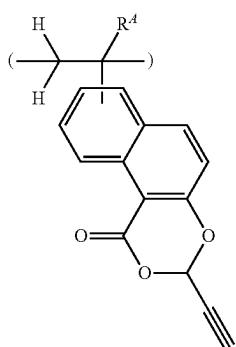
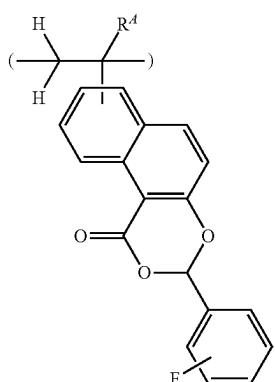
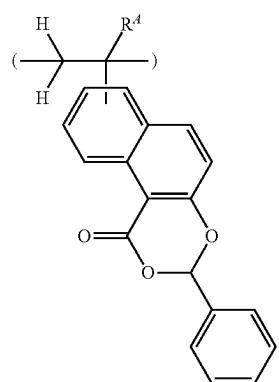
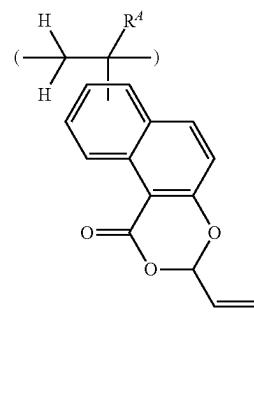
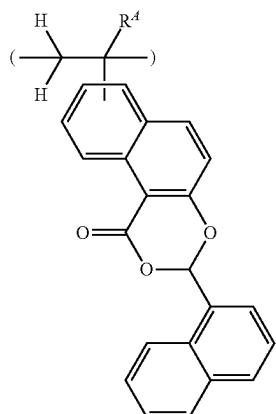
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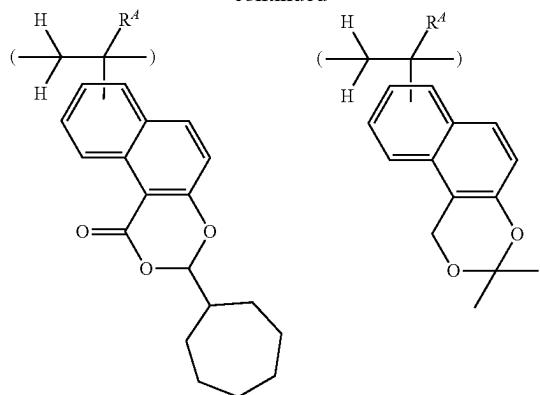
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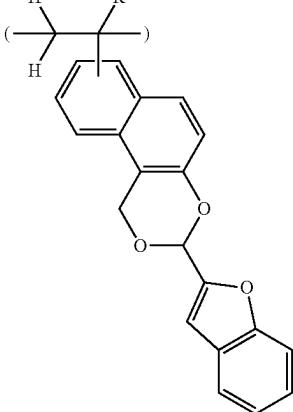
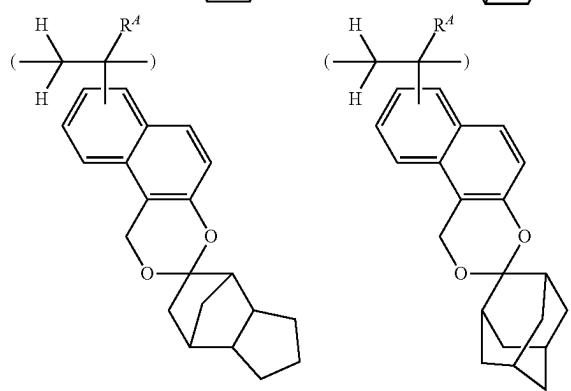
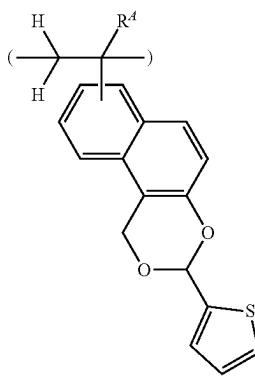
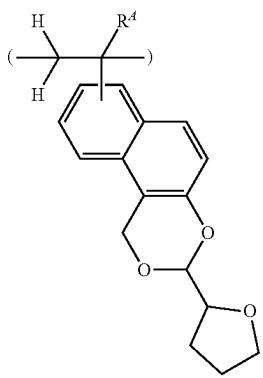
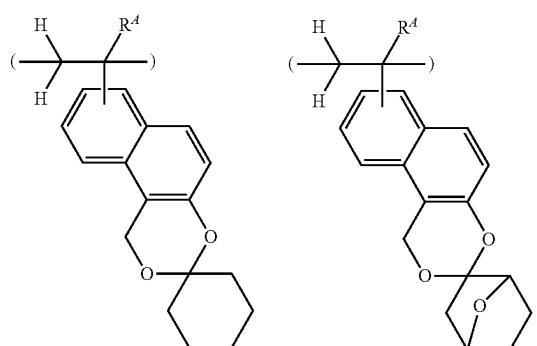
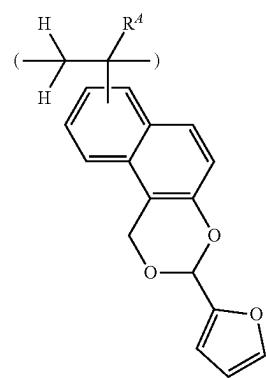
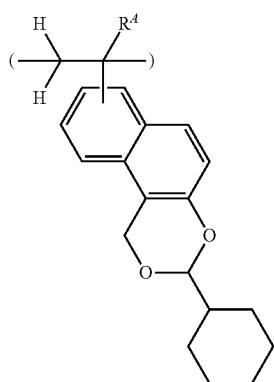
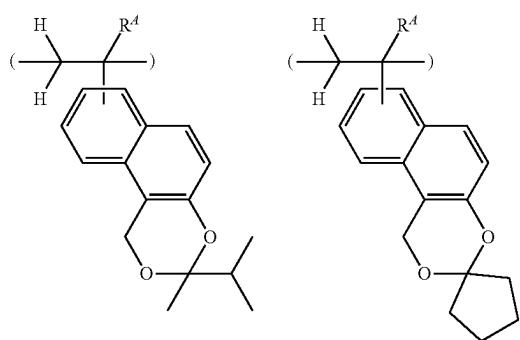
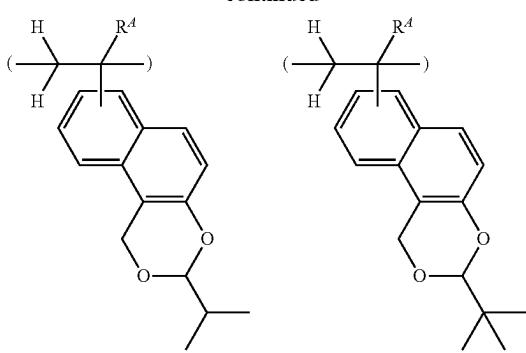
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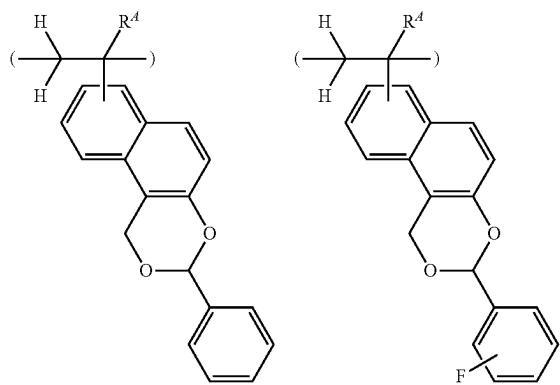
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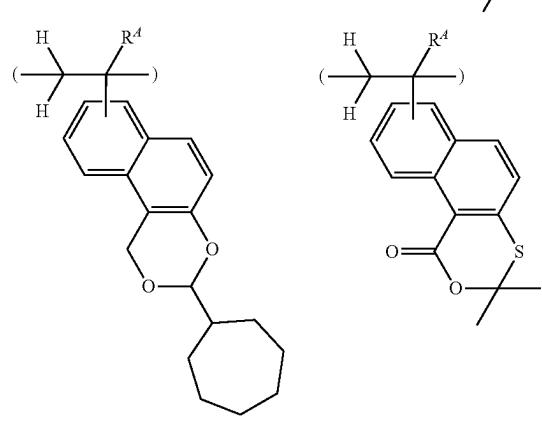
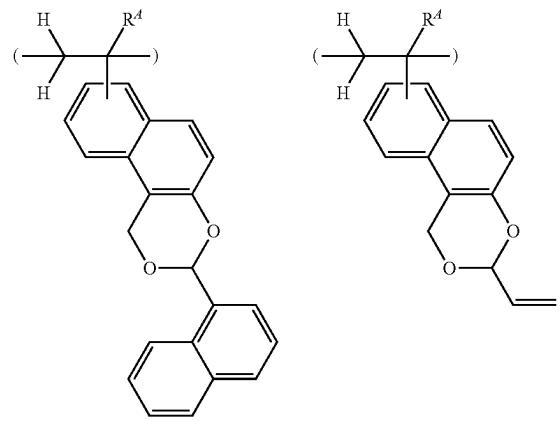
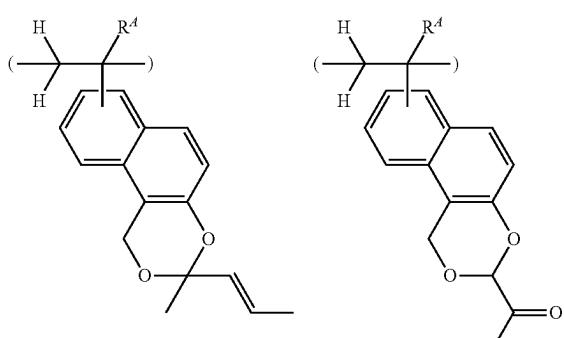
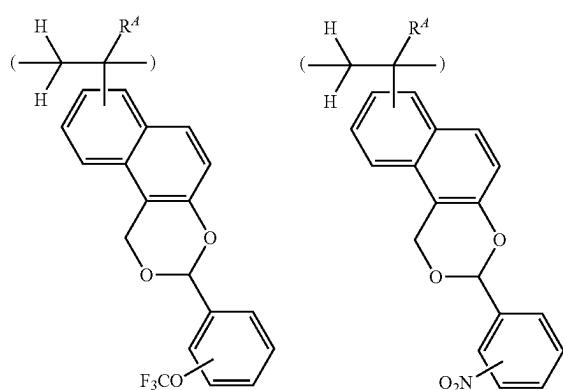
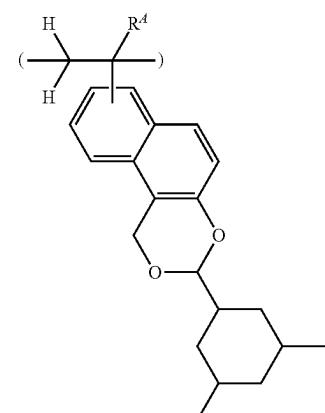
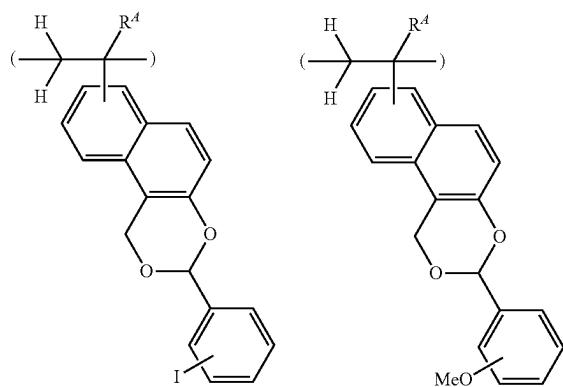
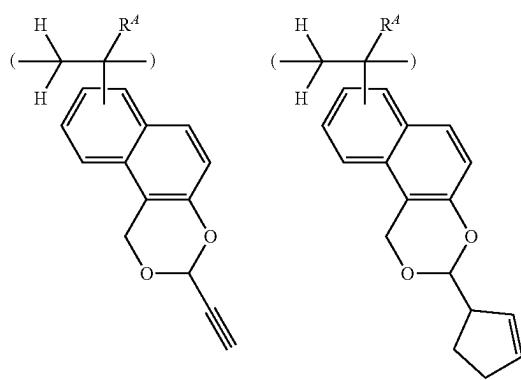
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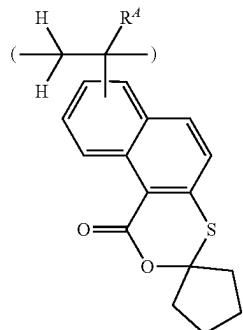
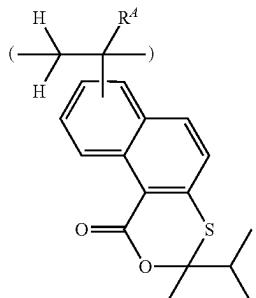
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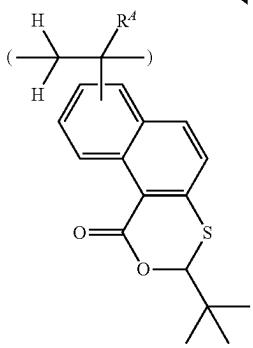
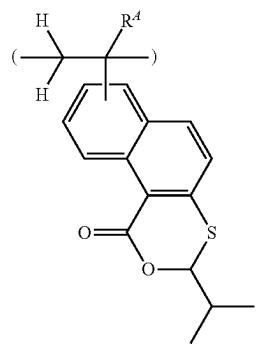
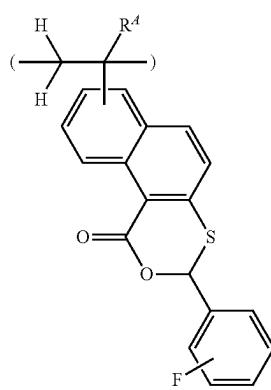
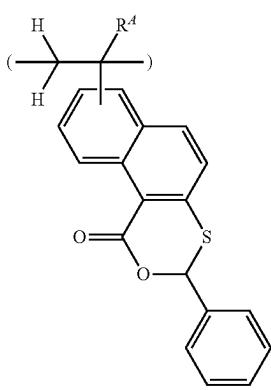
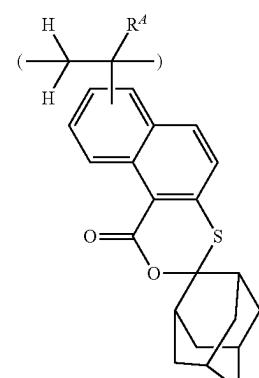
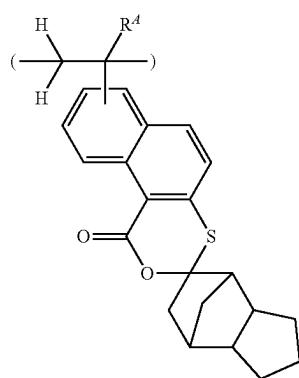
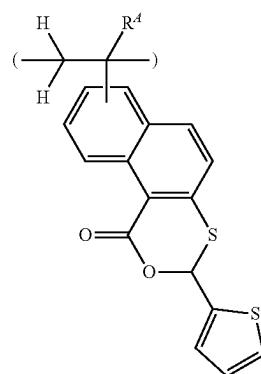
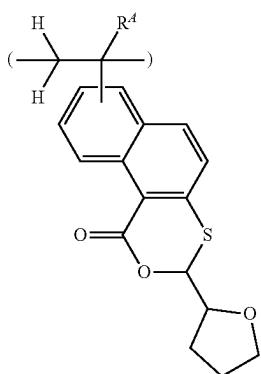
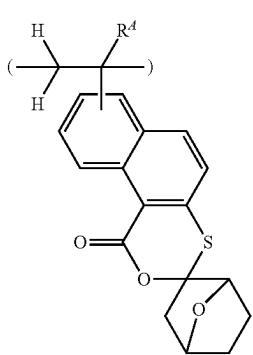
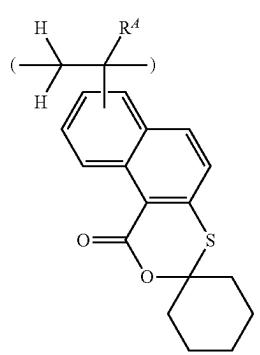
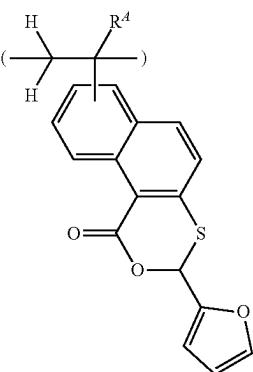
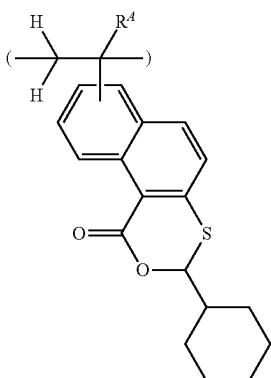
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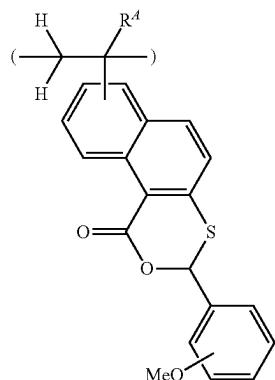
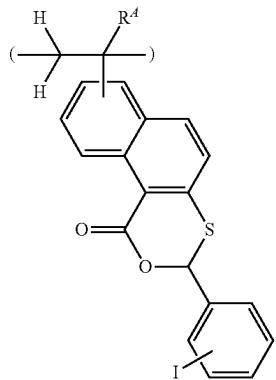
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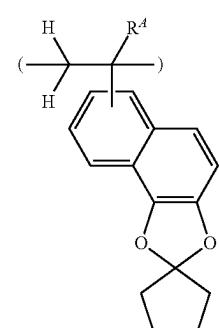
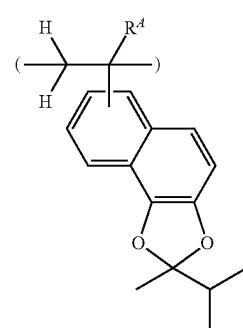
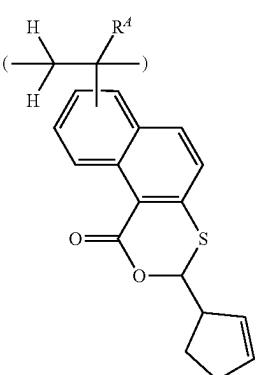
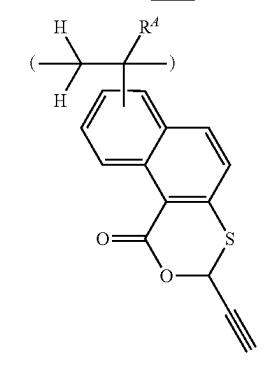
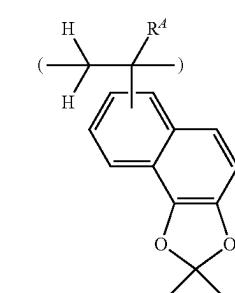
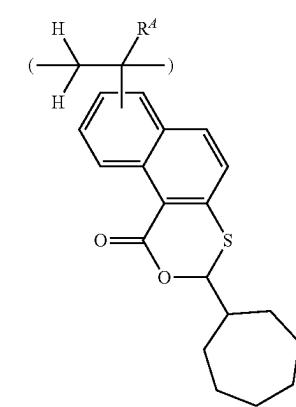
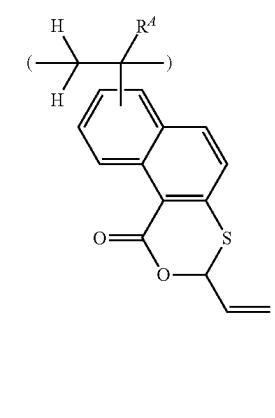
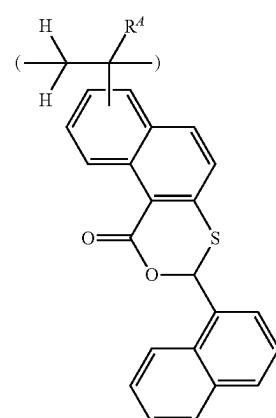
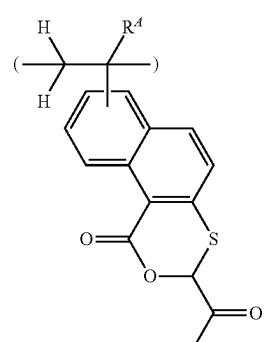
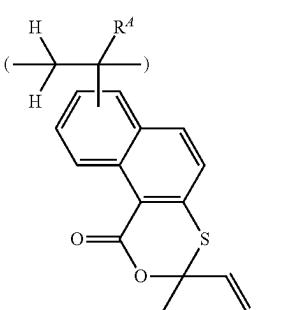
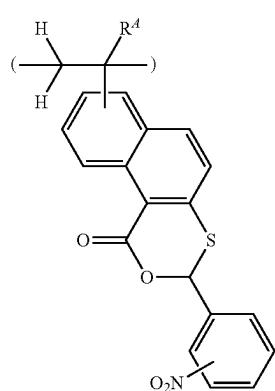
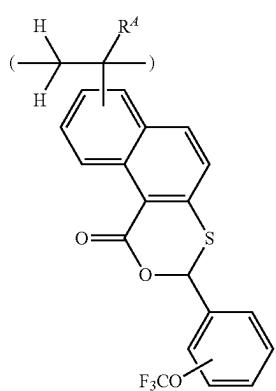
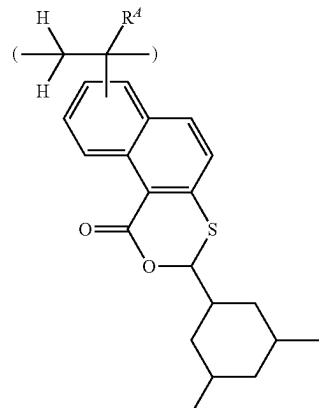
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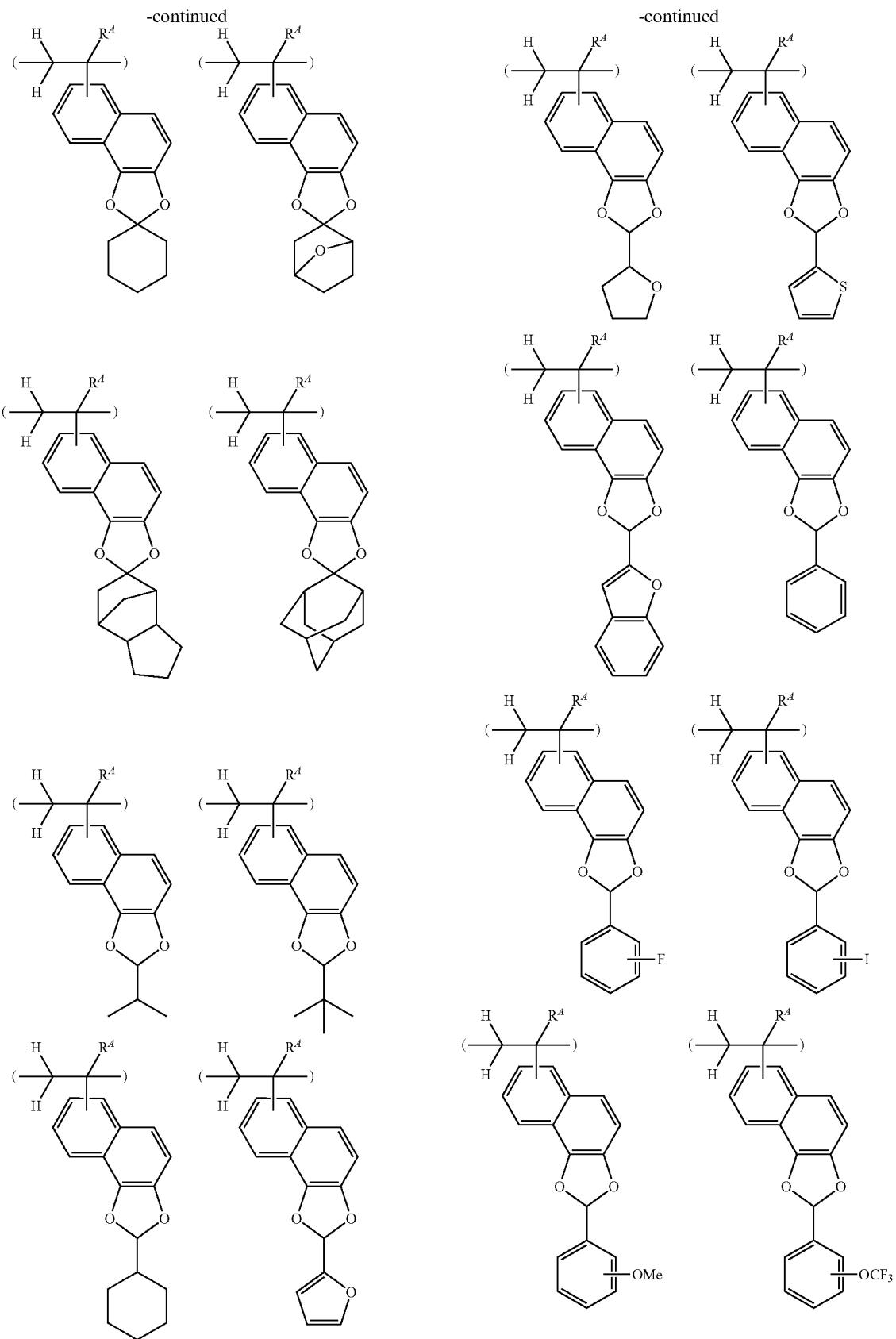


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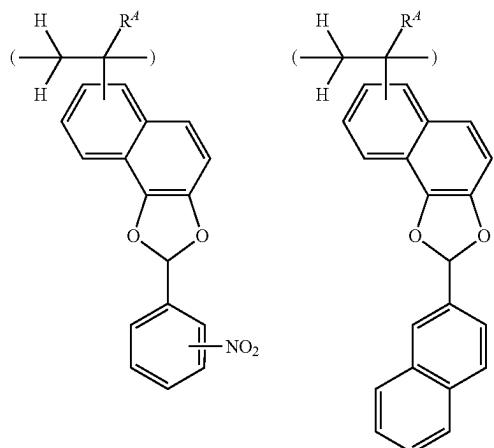


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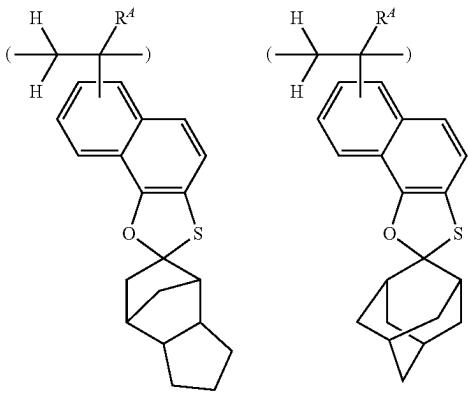
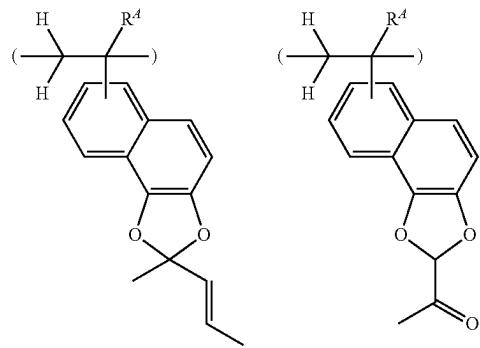
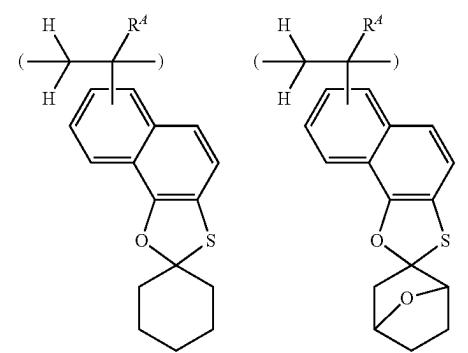
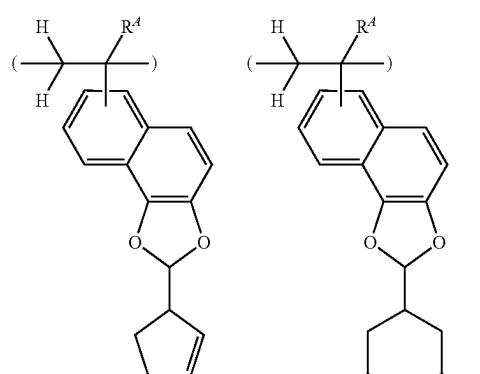
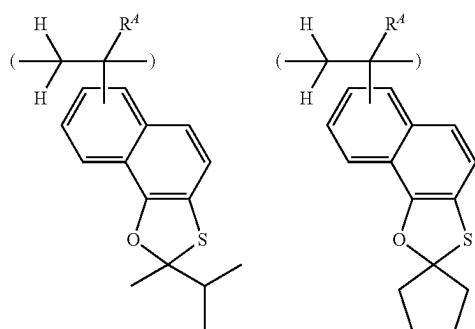
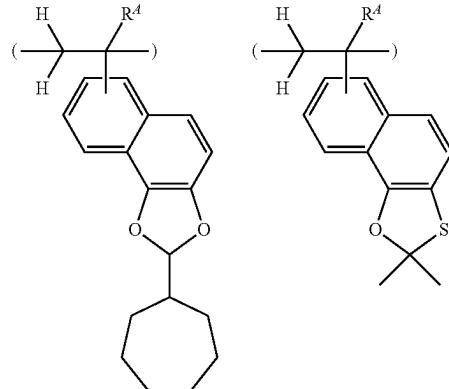




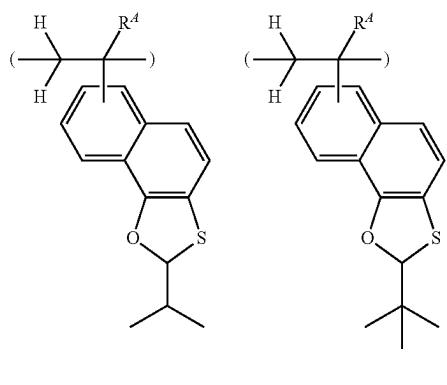
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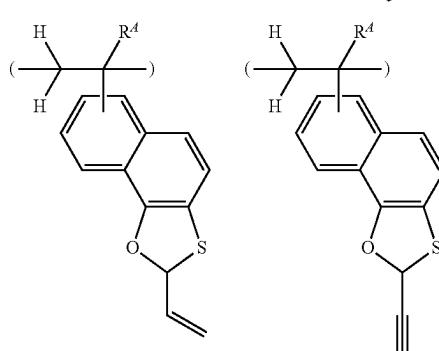
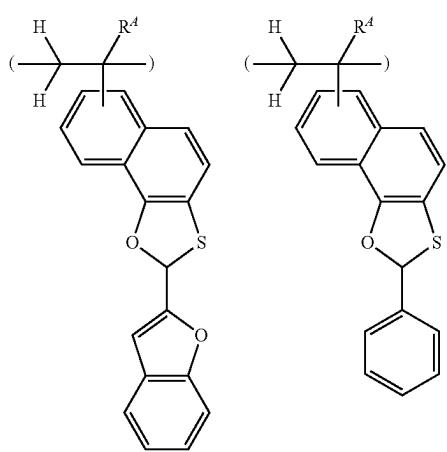
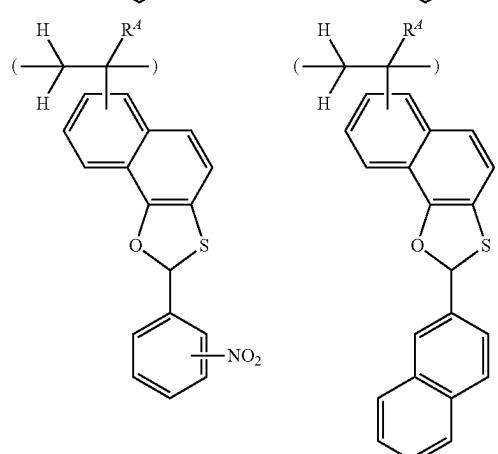
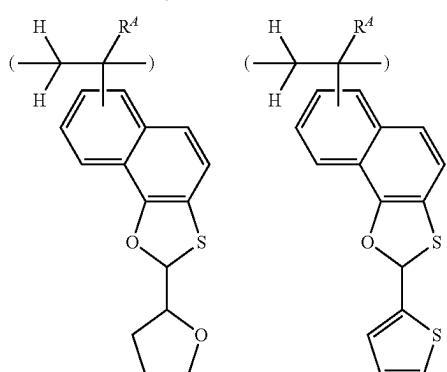
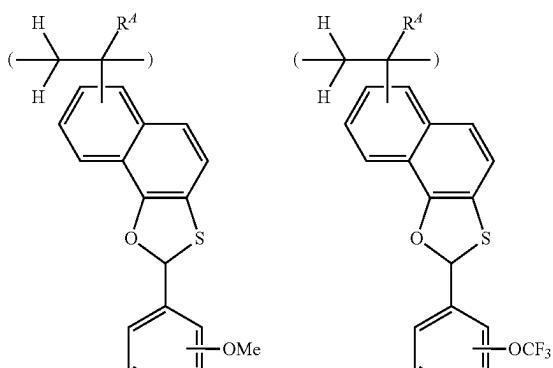
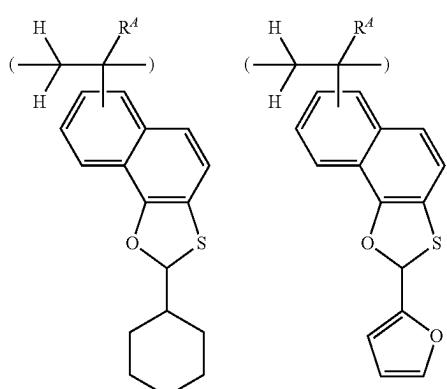
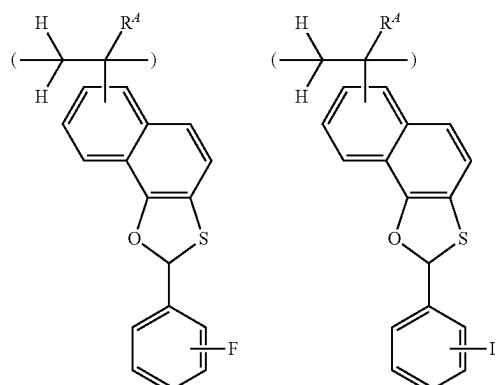
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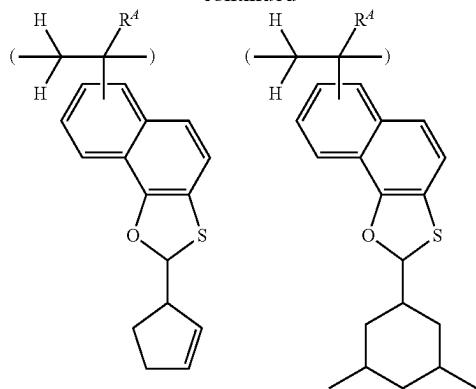
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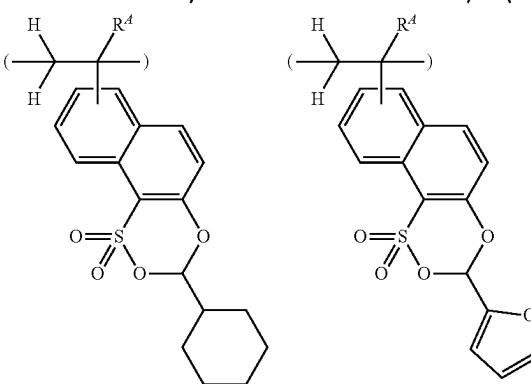
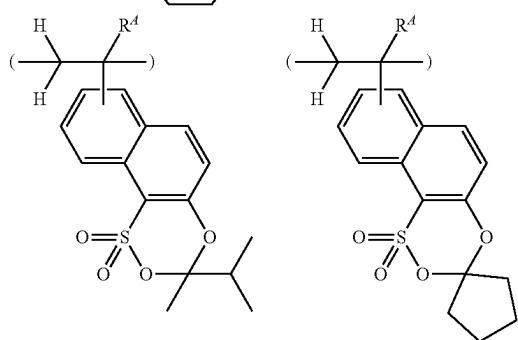
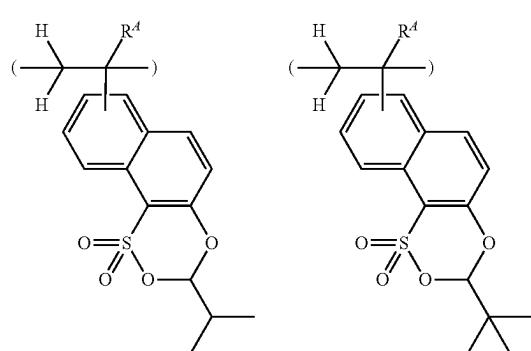
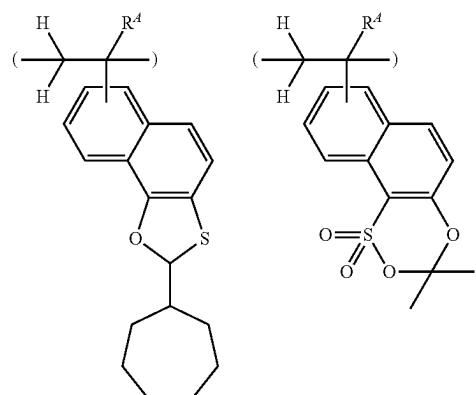
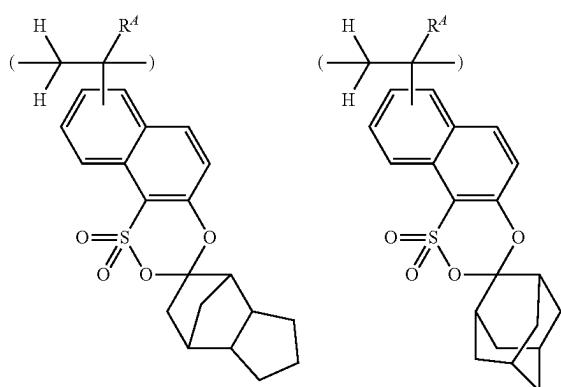
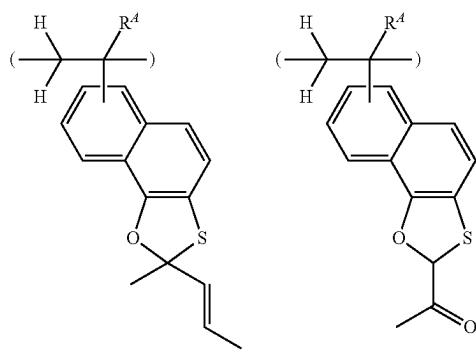
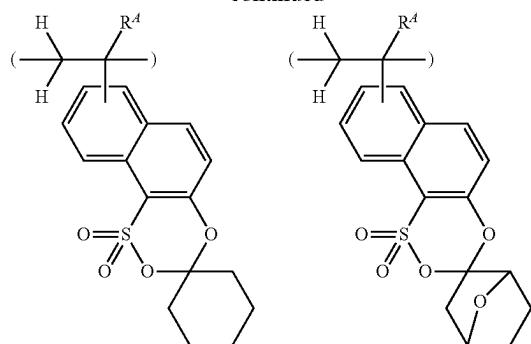
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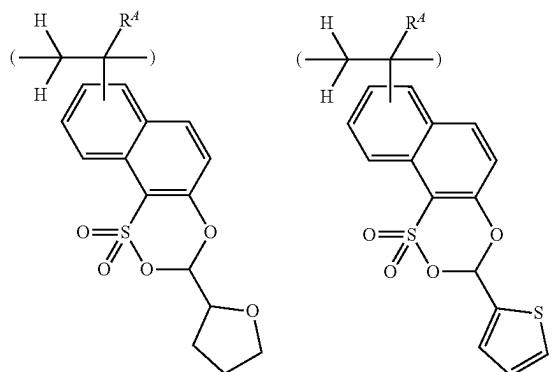
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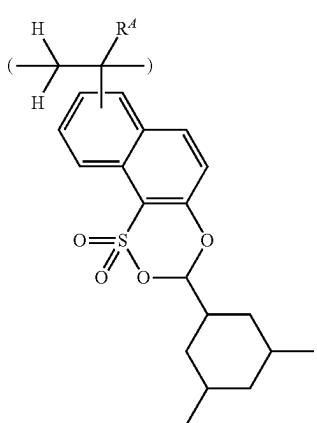
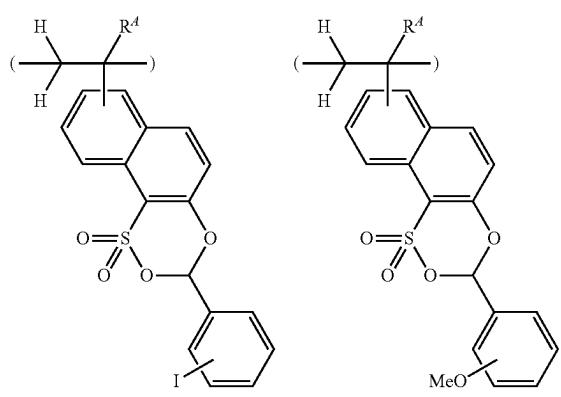
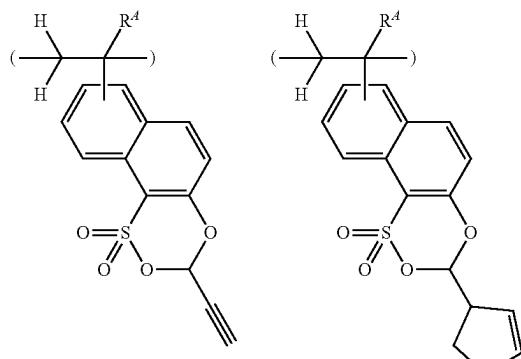
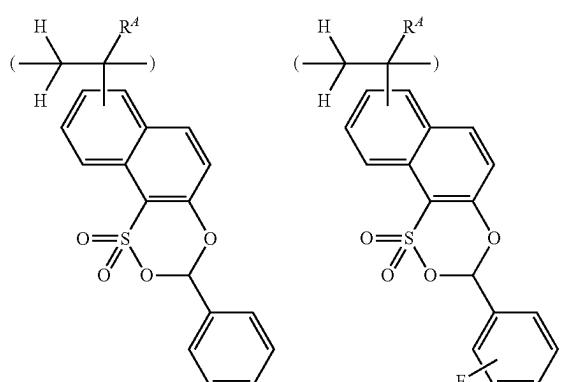
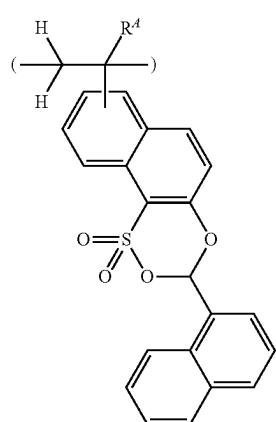
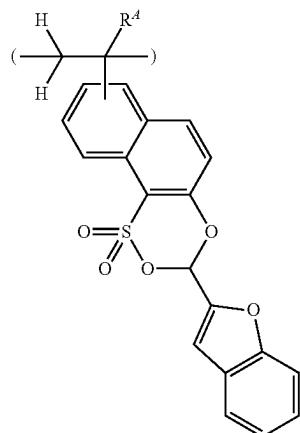
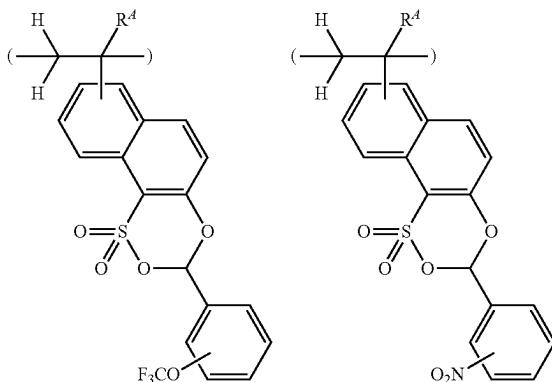
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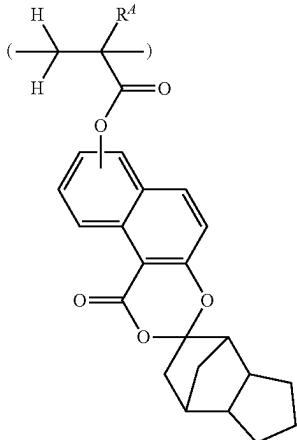
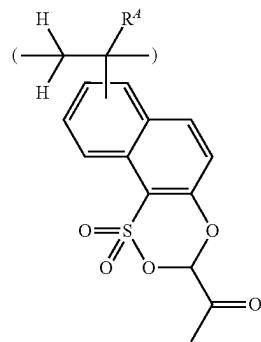
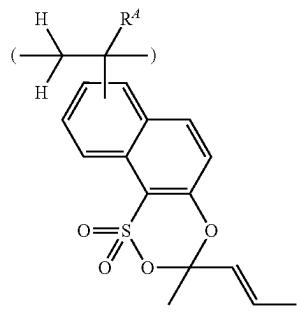
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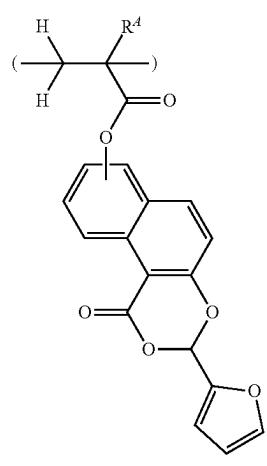
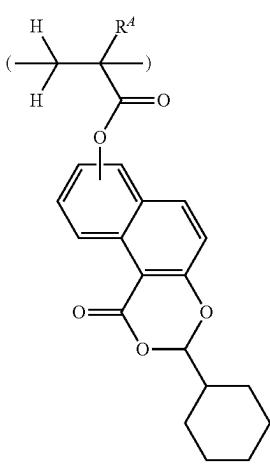
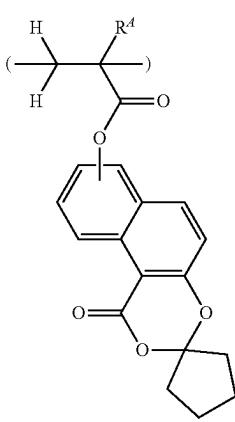
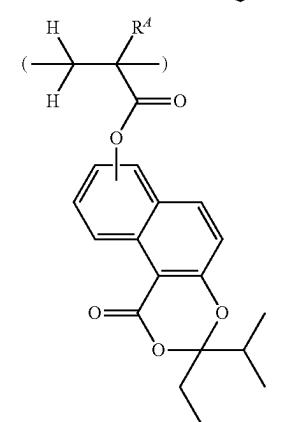
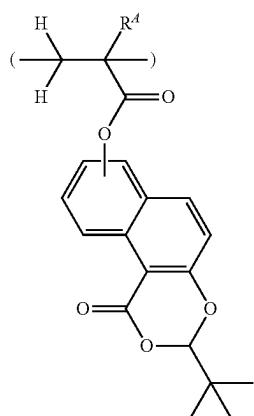
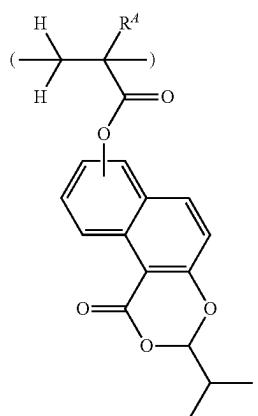
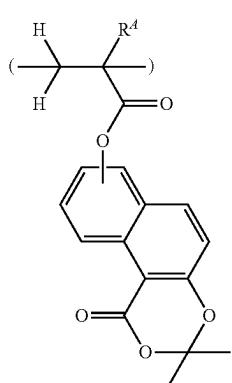
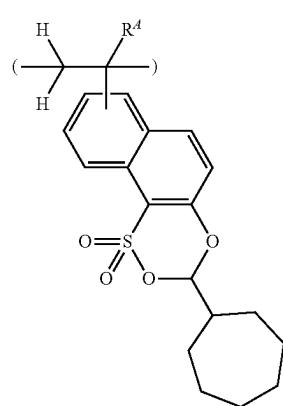
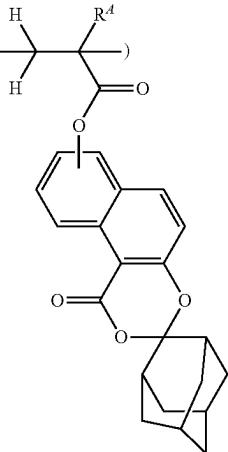
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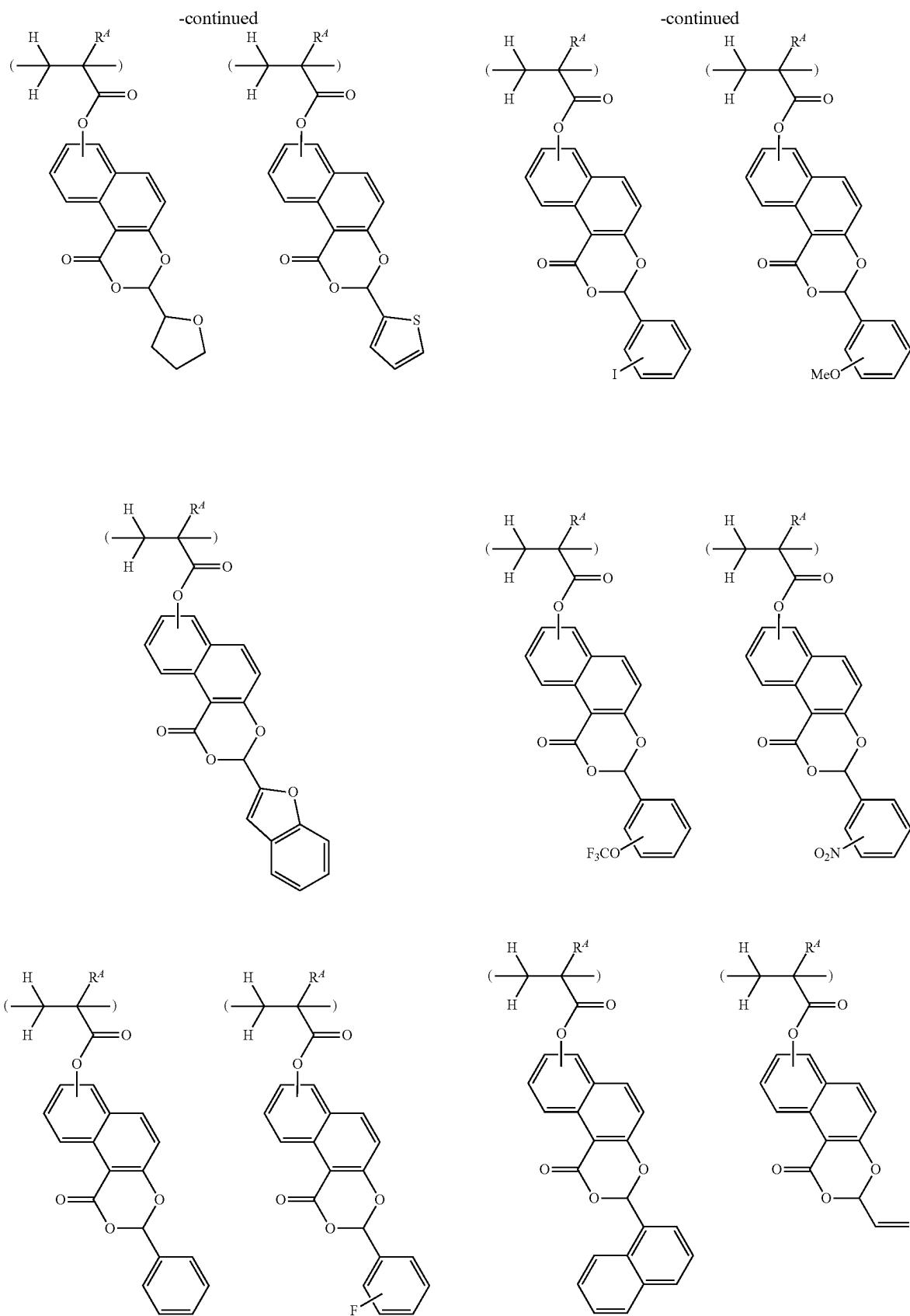


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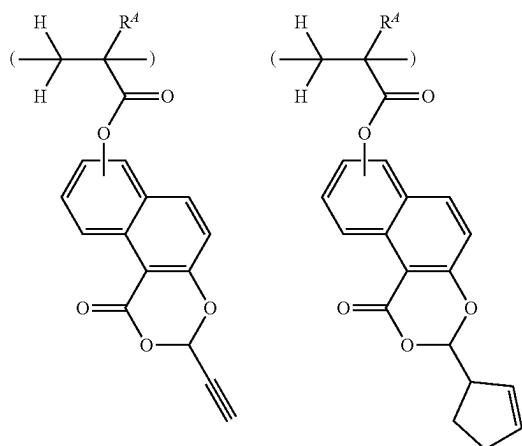


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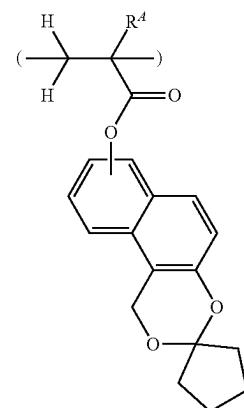
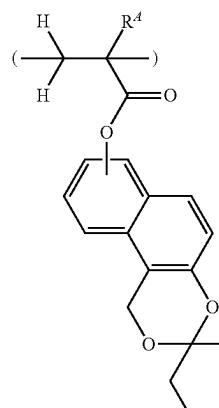
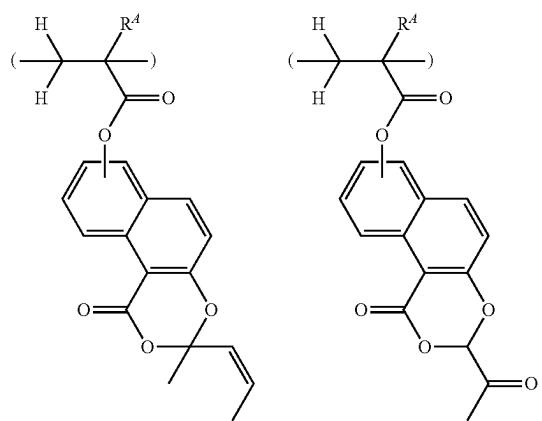
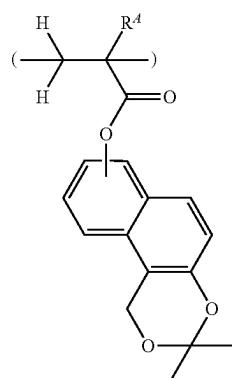
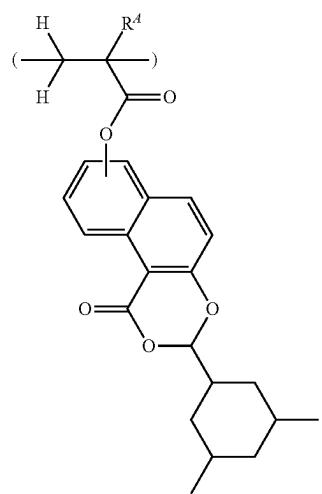
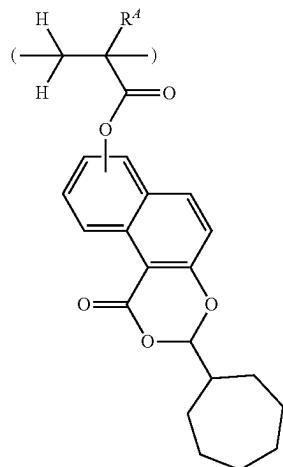




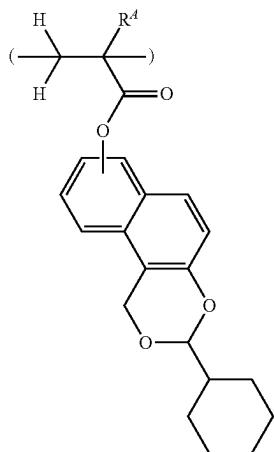
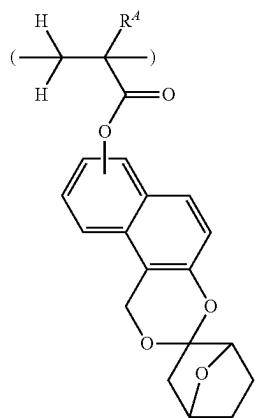
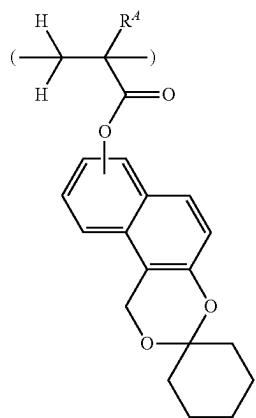
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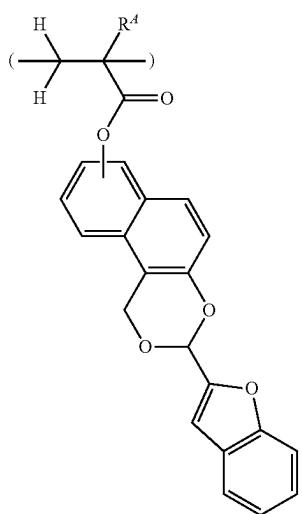
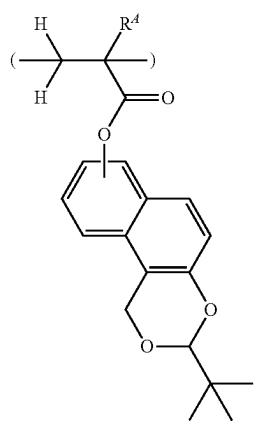
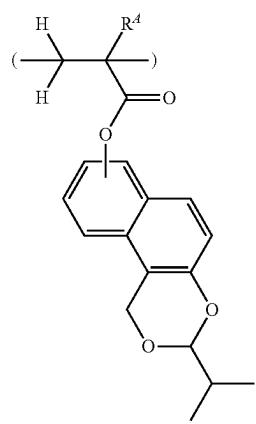
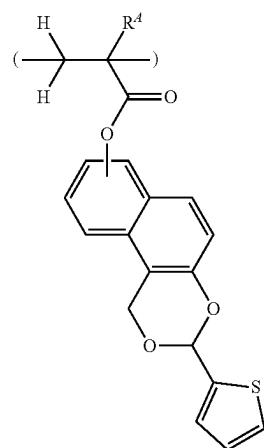
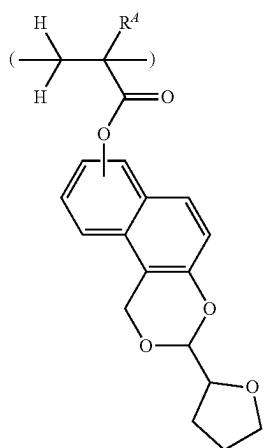
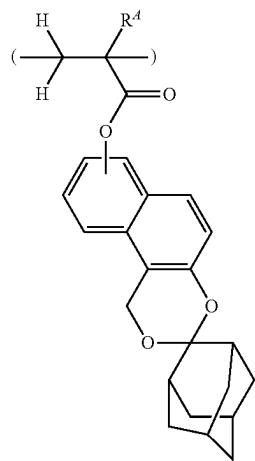
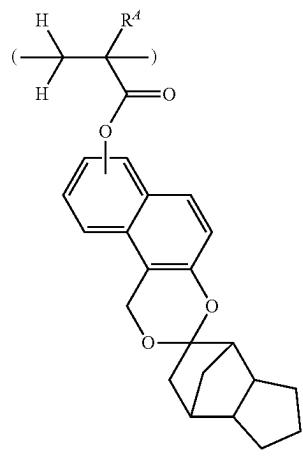
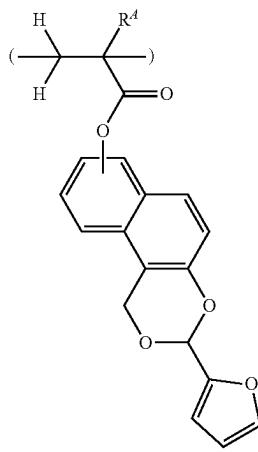
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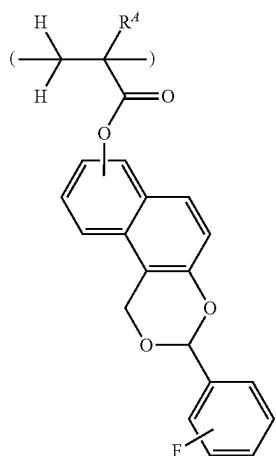
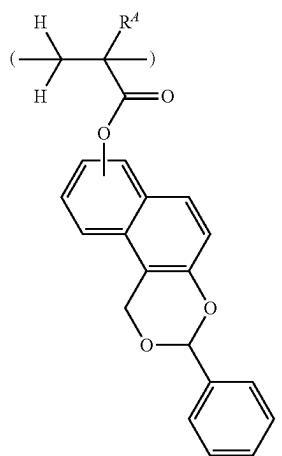
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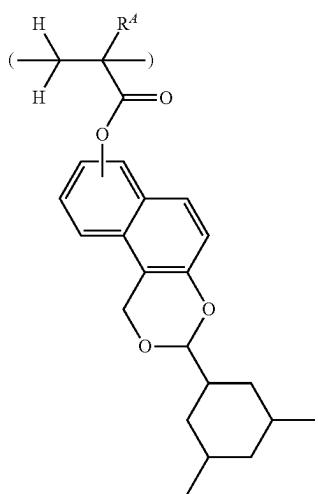
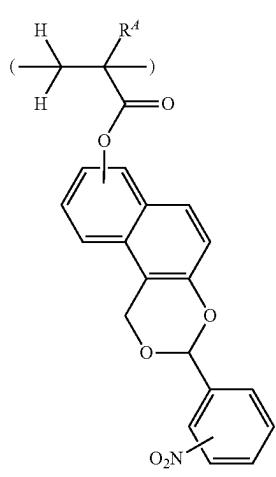
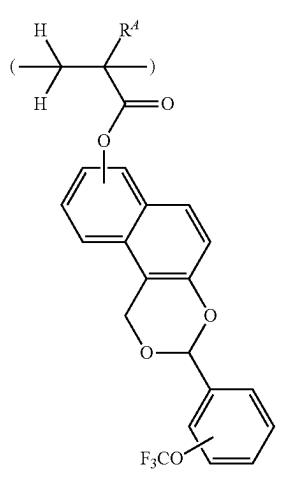
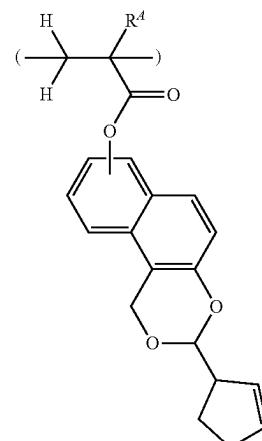
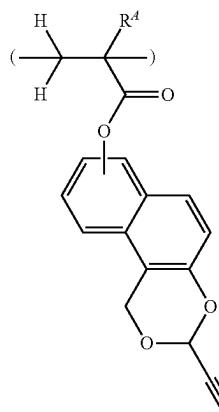
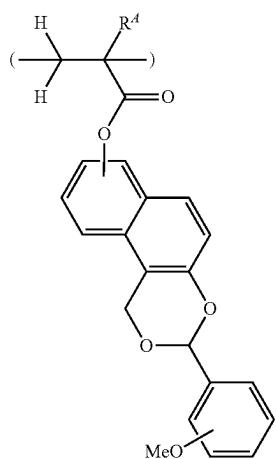
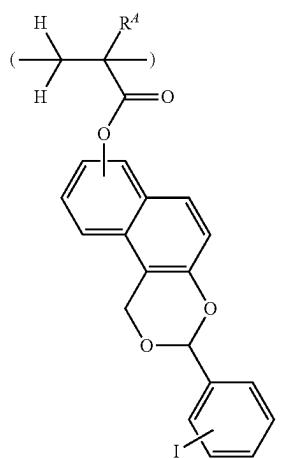
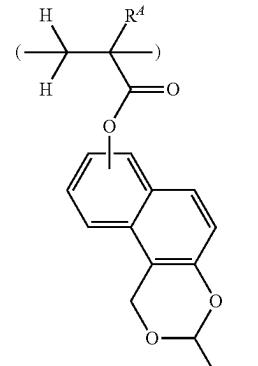
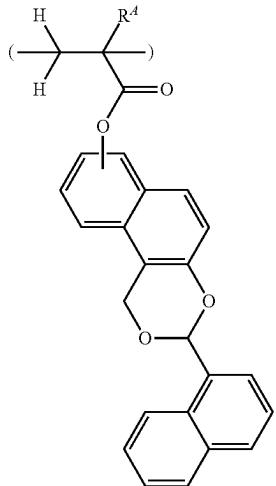
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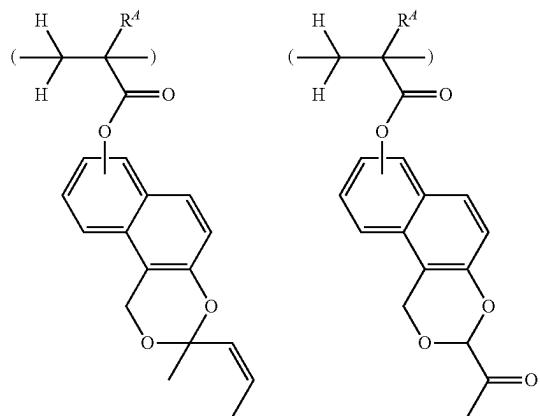
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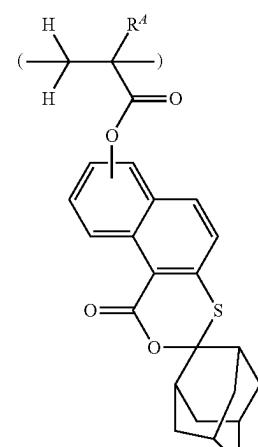
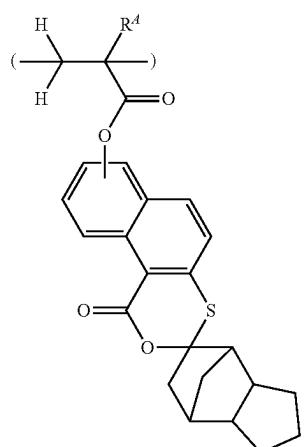
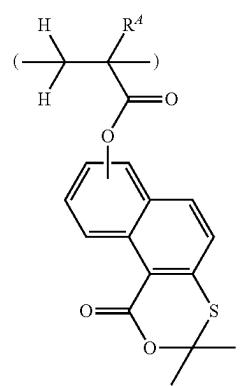
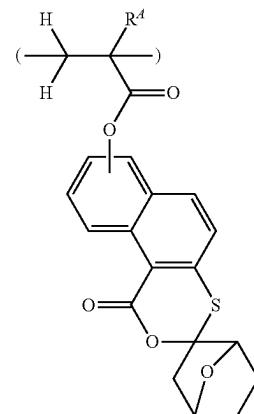
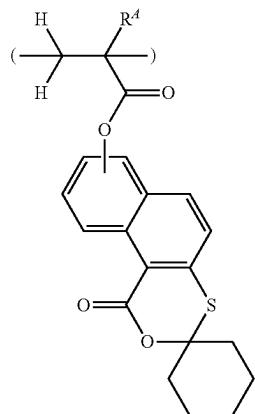
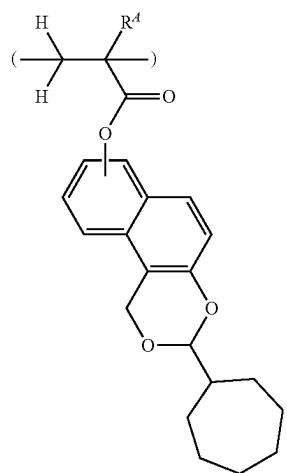
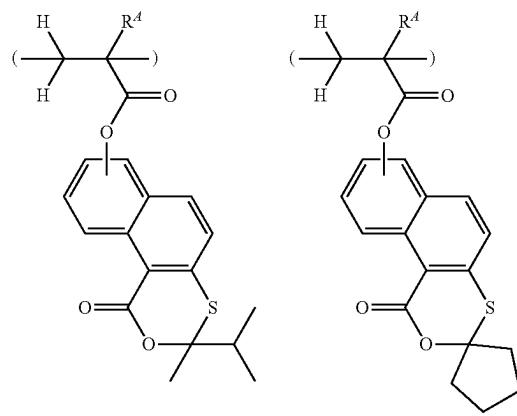
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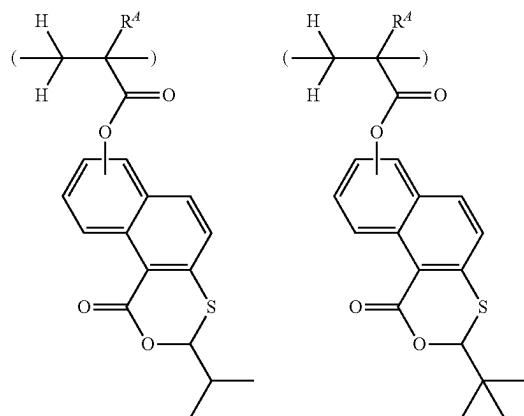
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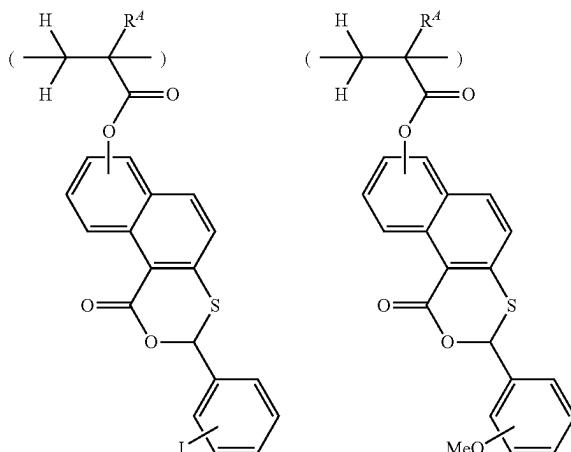
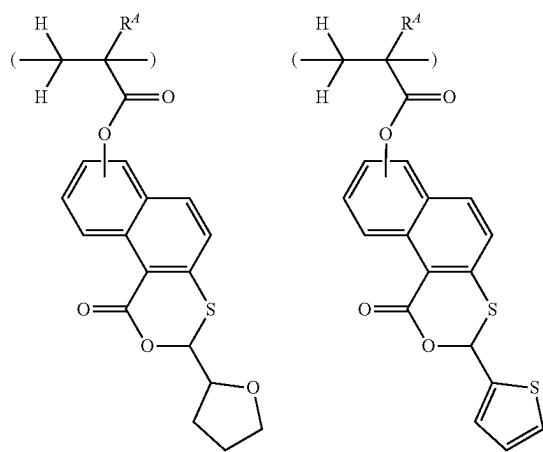
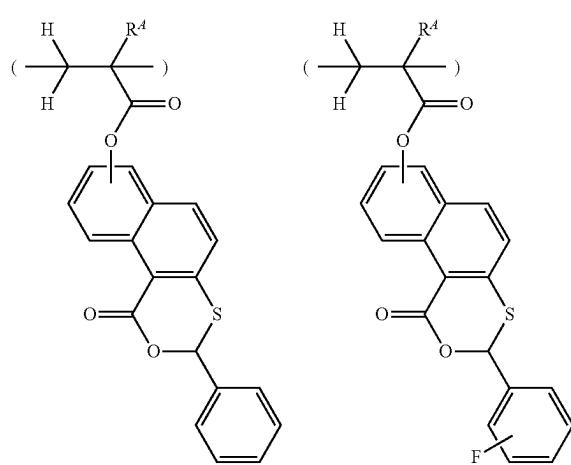
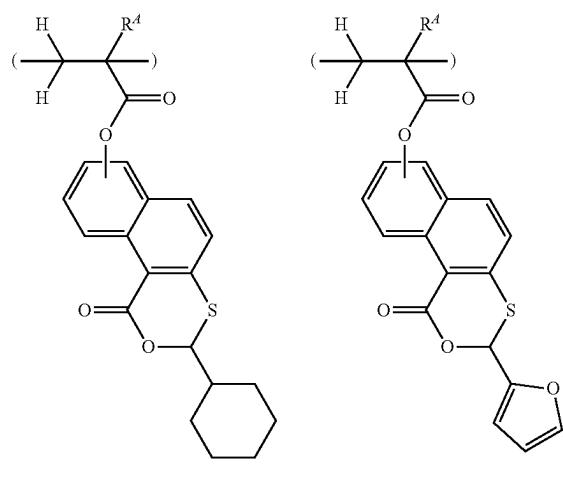
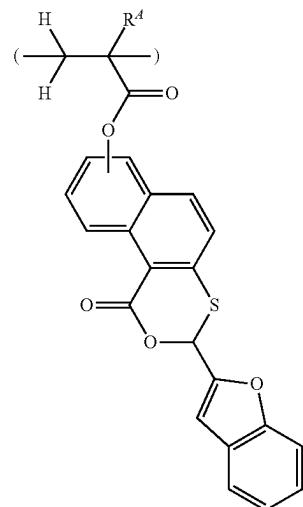
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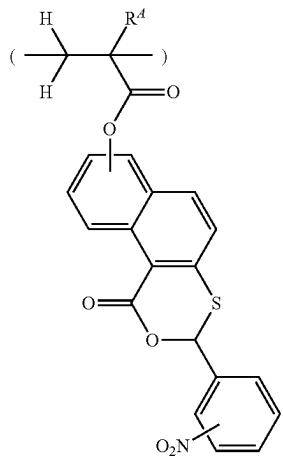
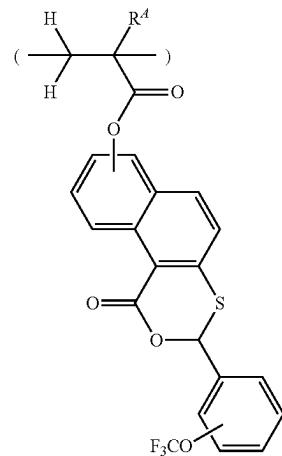
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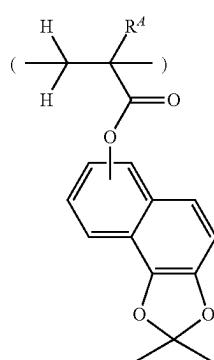
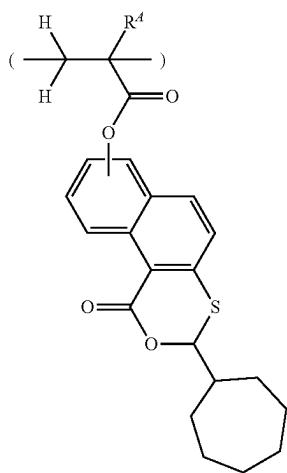
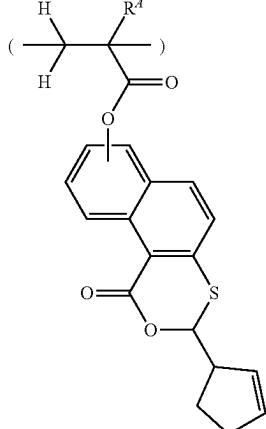
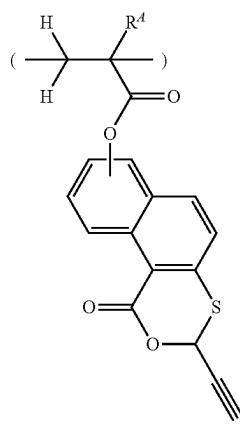
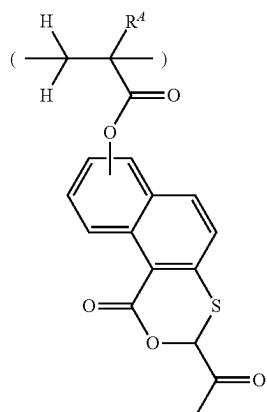
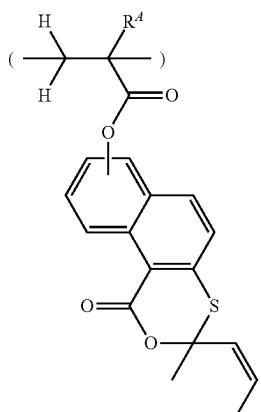
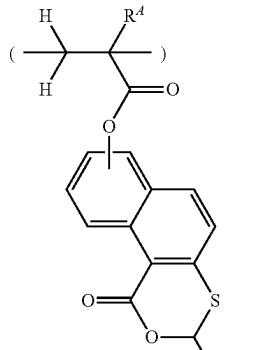
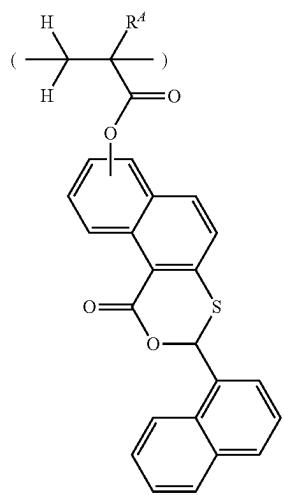
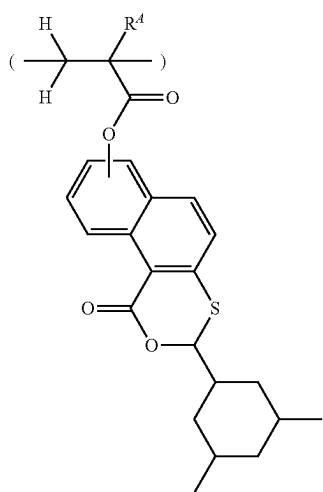
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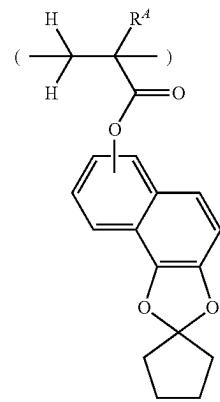
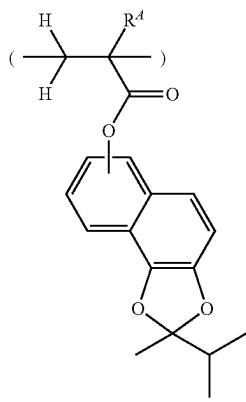
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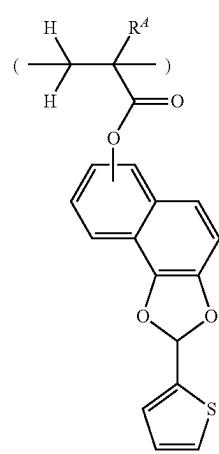
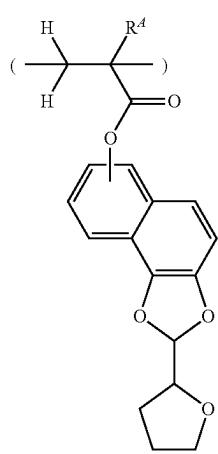
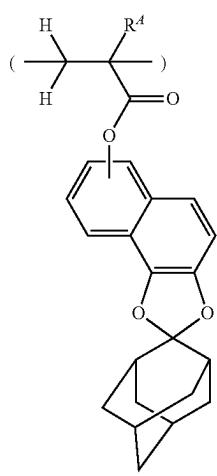
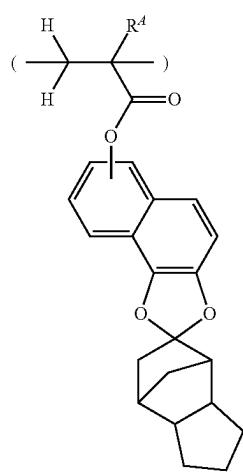
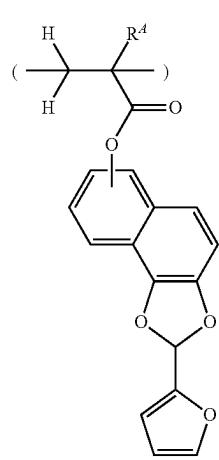
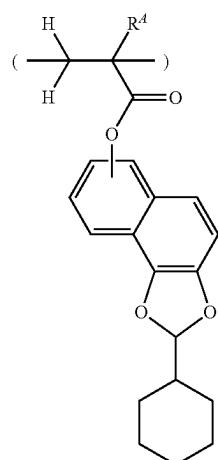
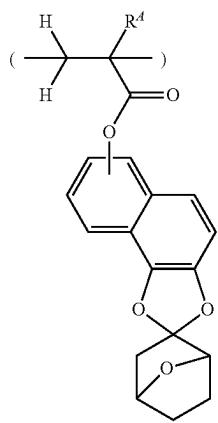
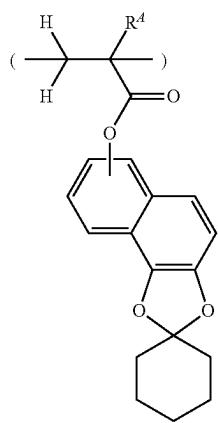
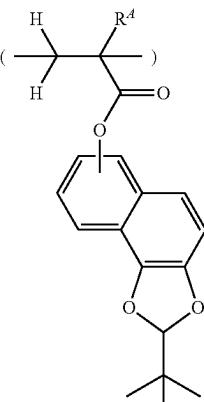
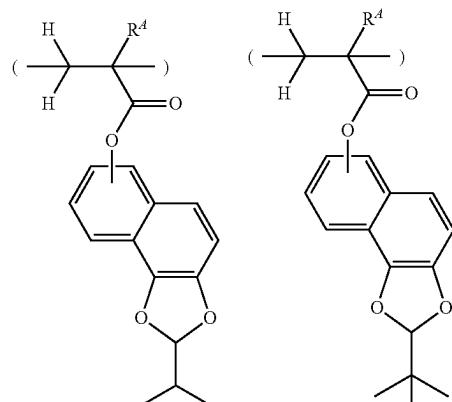
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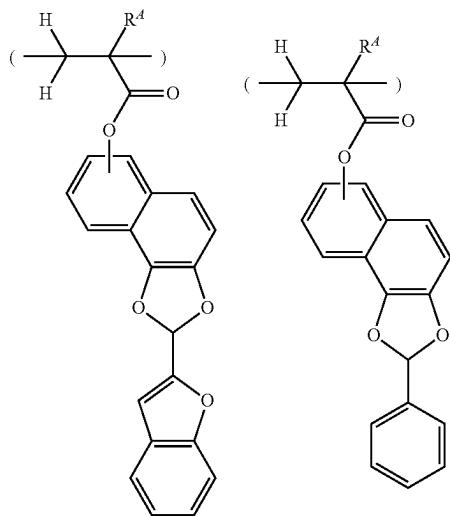
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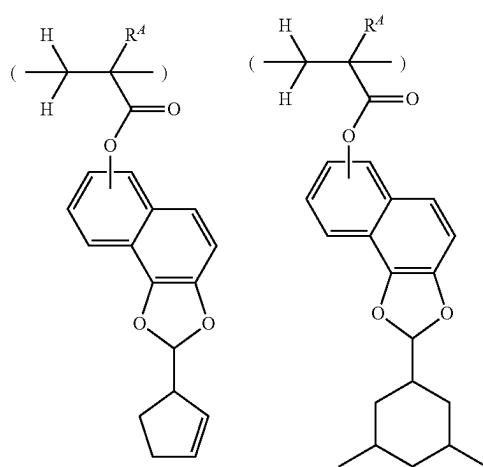
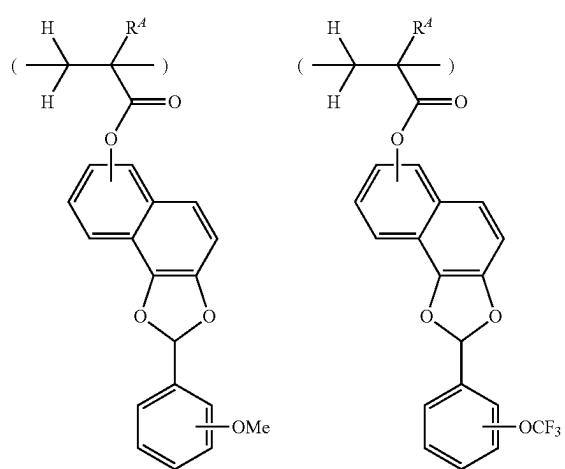
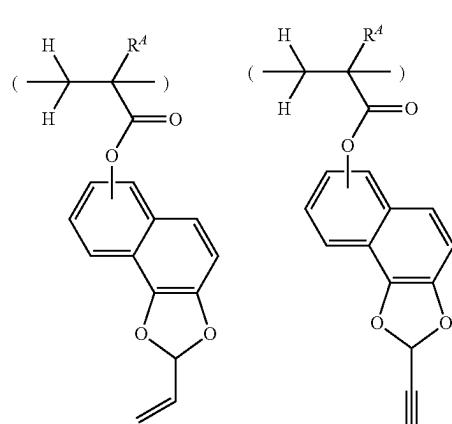
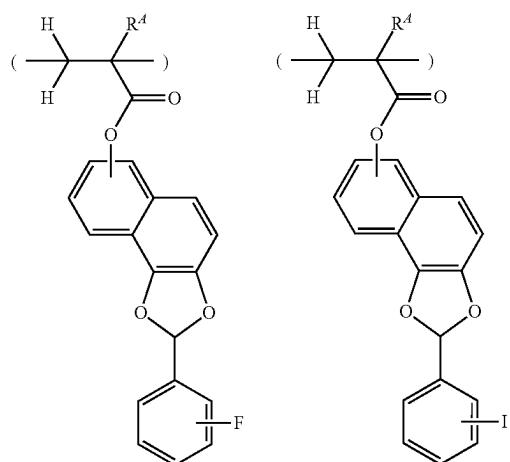
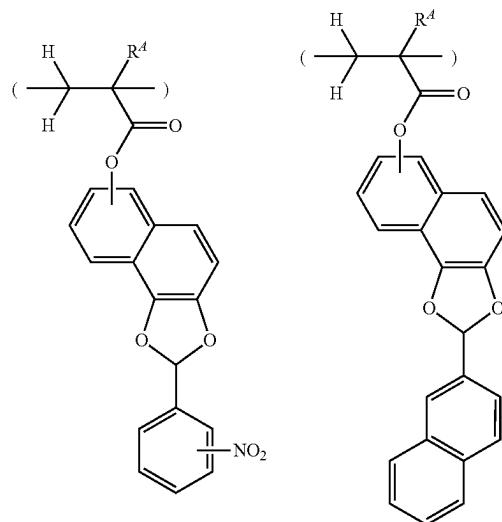
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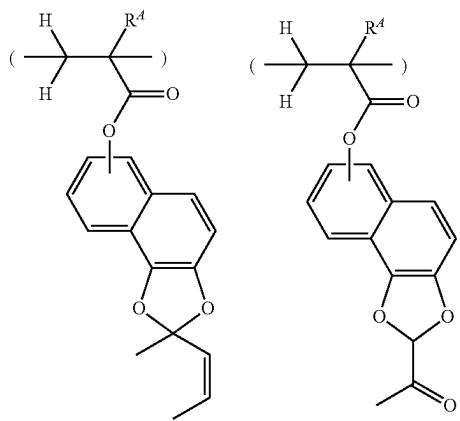
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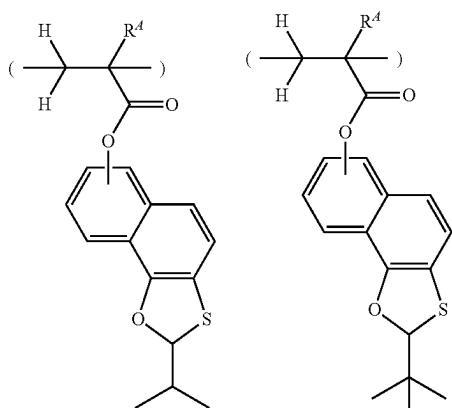
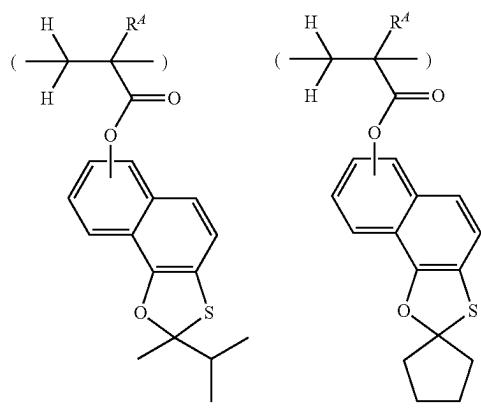
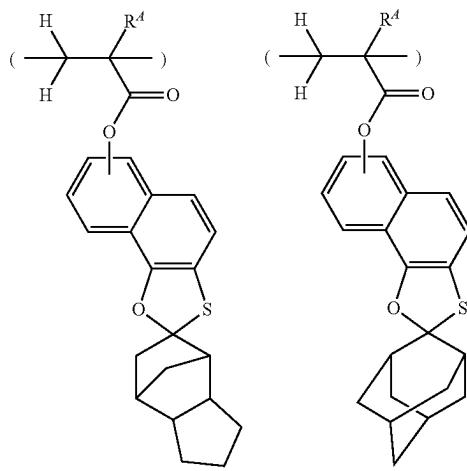
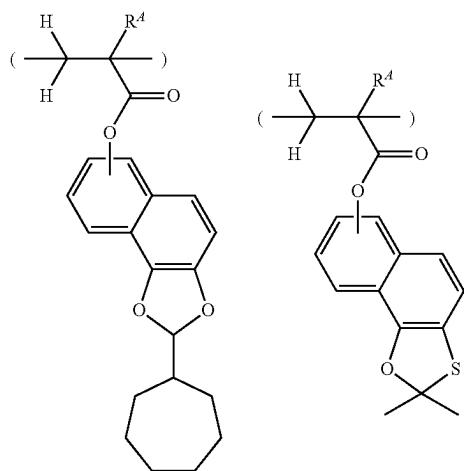
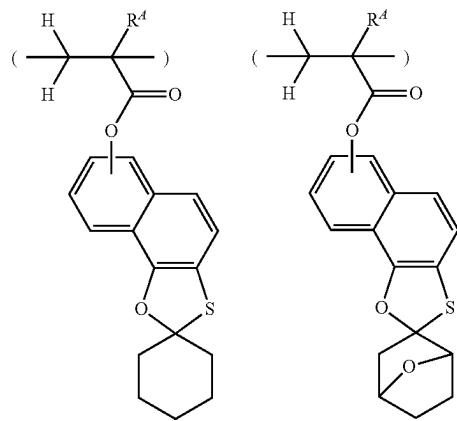
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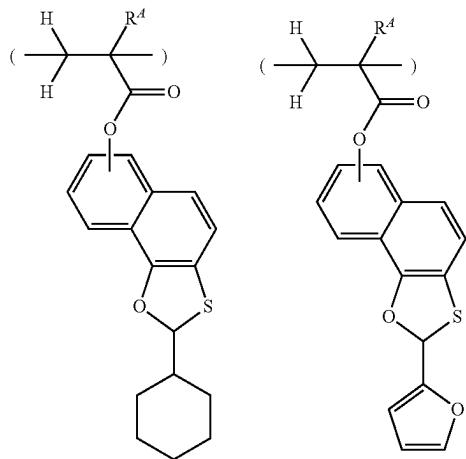
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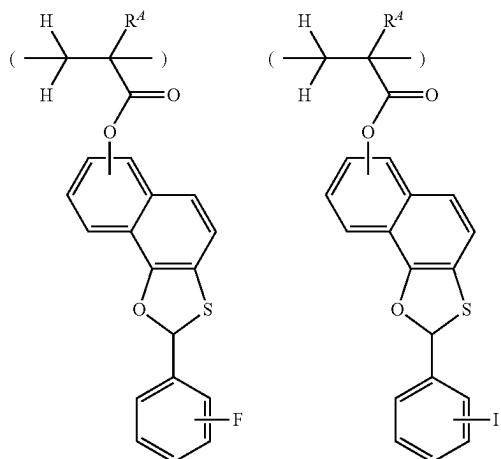
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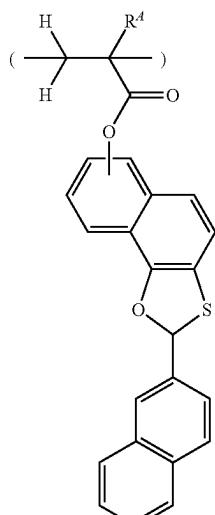
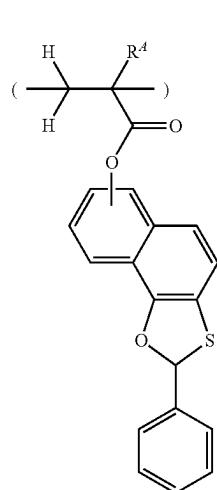
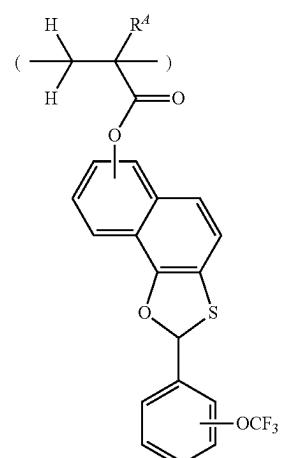
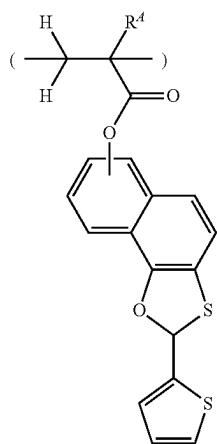
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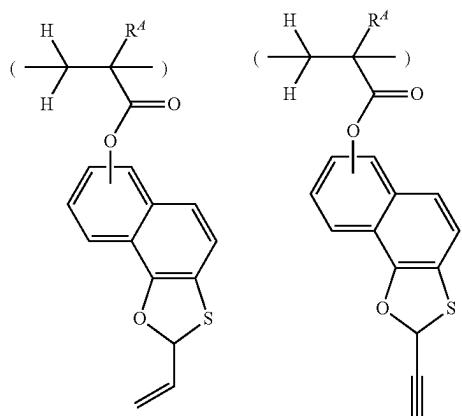
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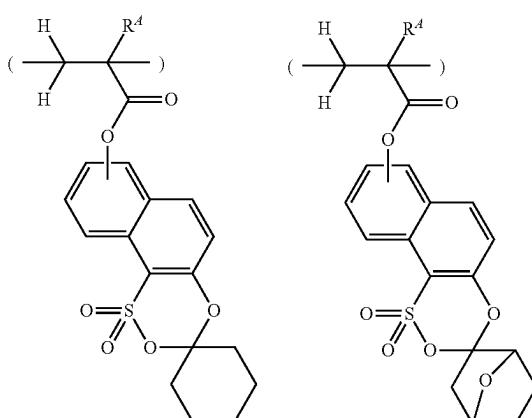
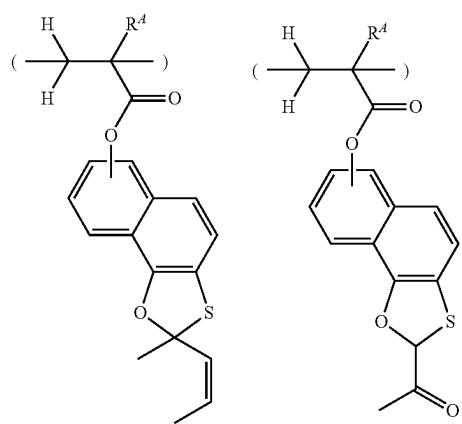
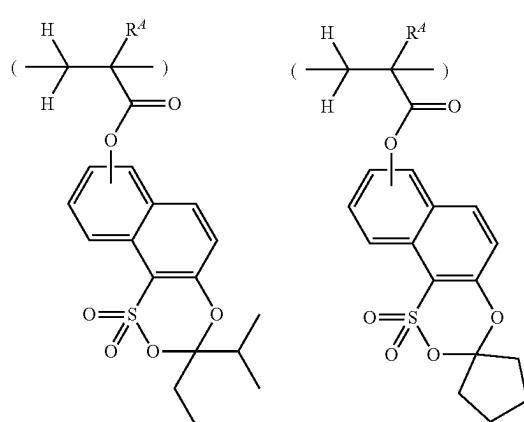
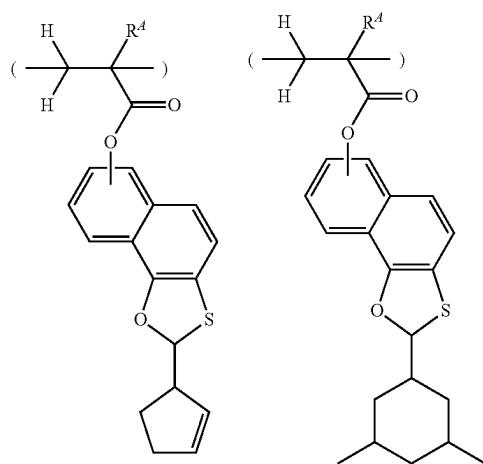
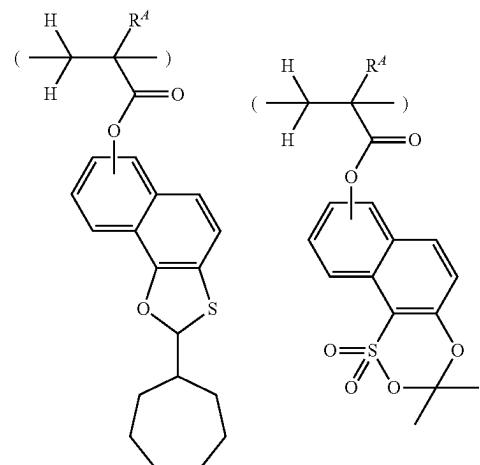
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 | \\
 \text{O} \\
 \text{---} \text{C}_6\text{H}_3\text{---} \text{C}_6\text{H}_4\text{---} \\
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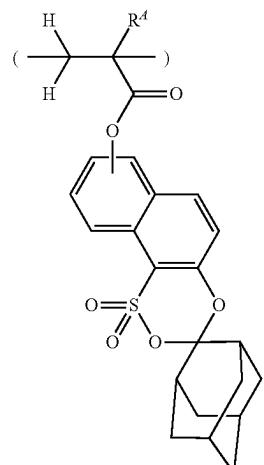
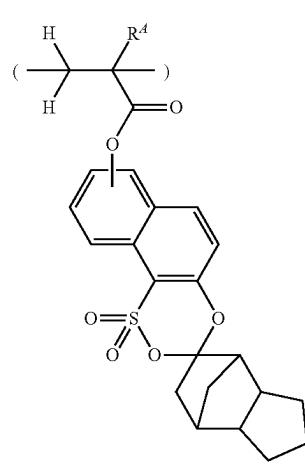
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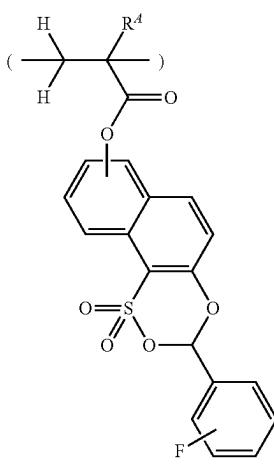
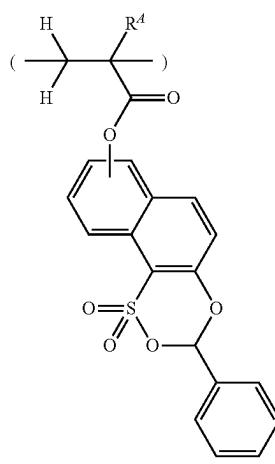
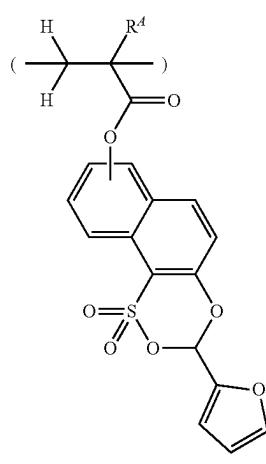
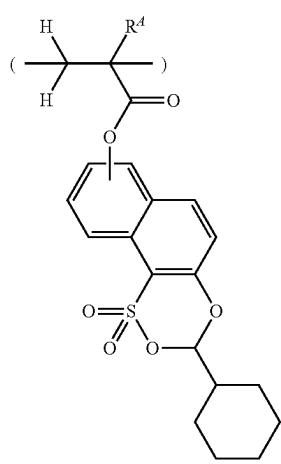
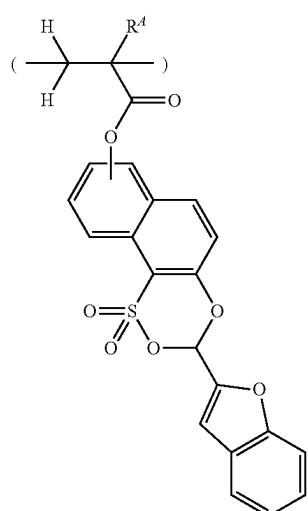
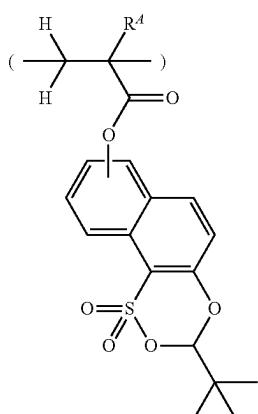
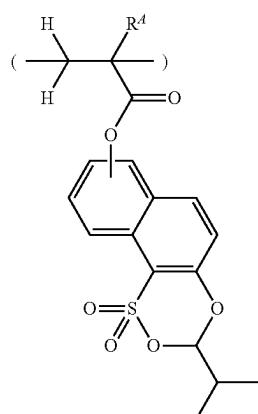
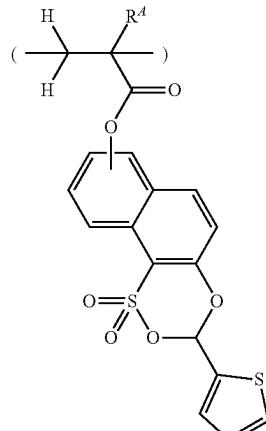
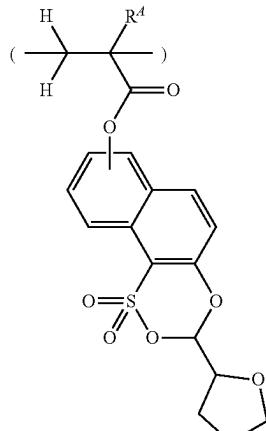
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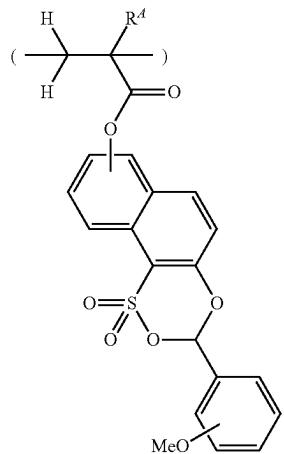
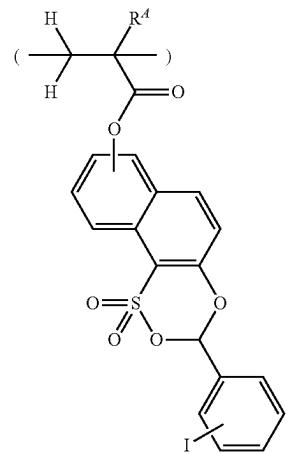
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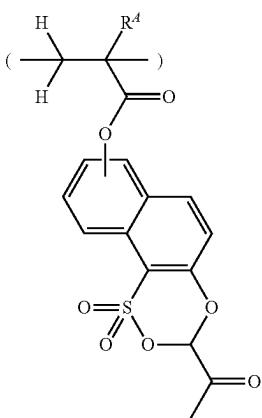
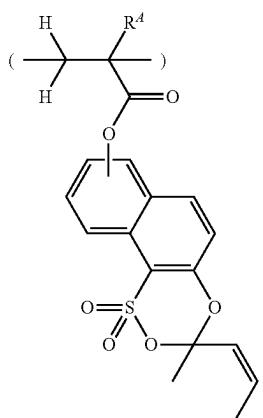
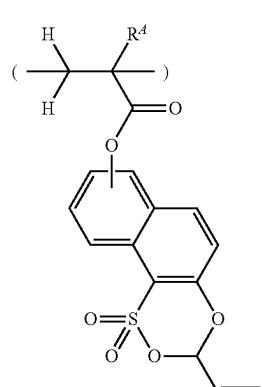
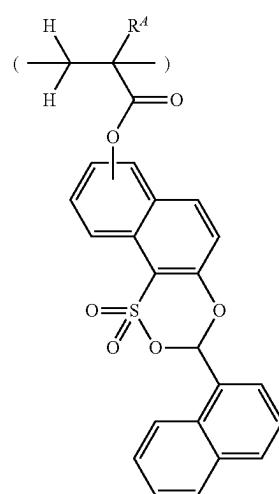
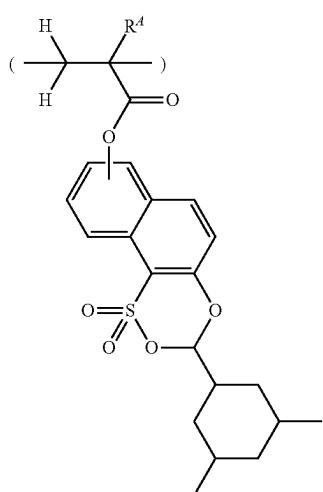
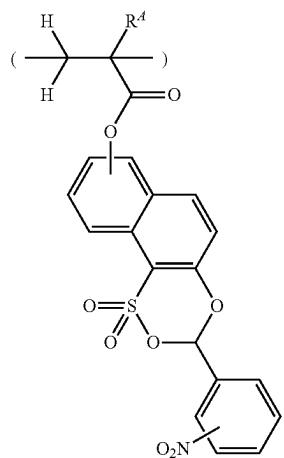
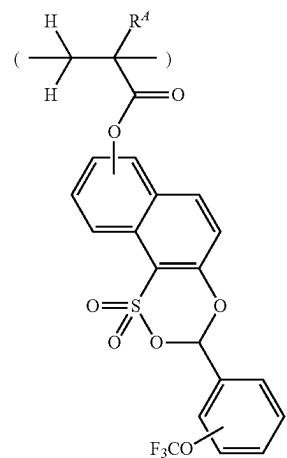
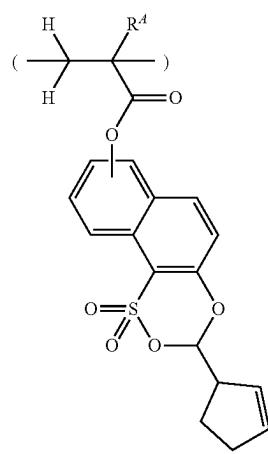
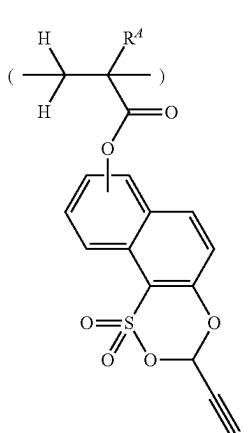
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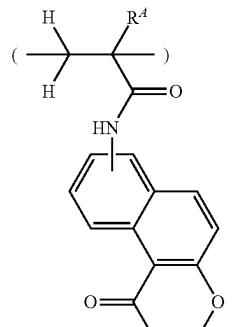
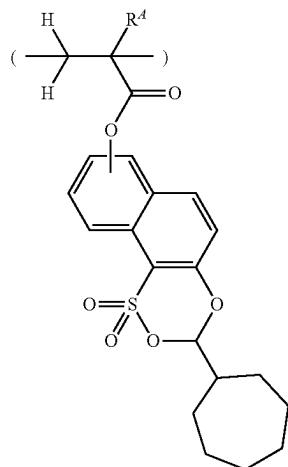
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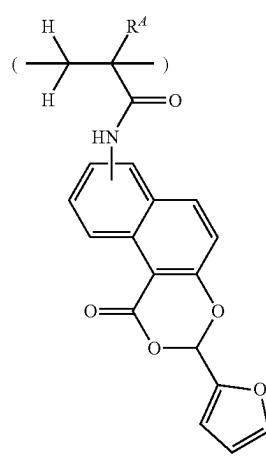
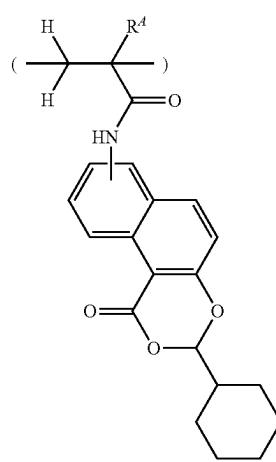
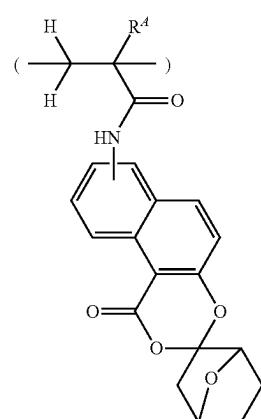
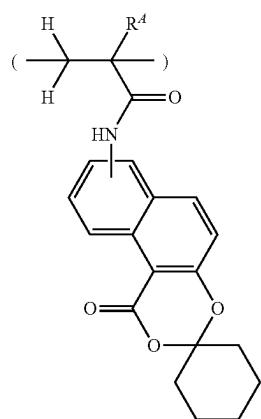
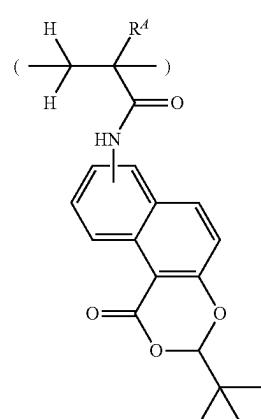
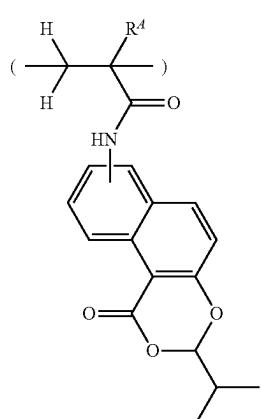
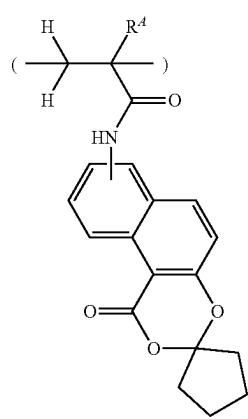
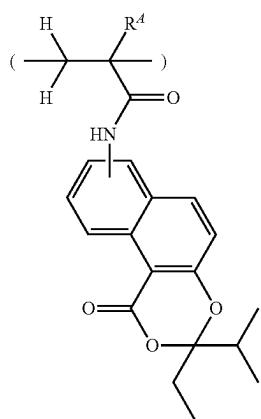
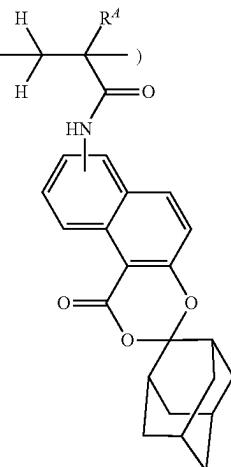
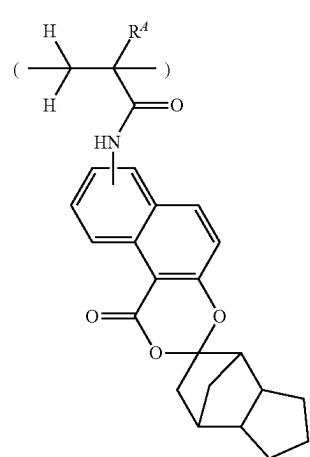
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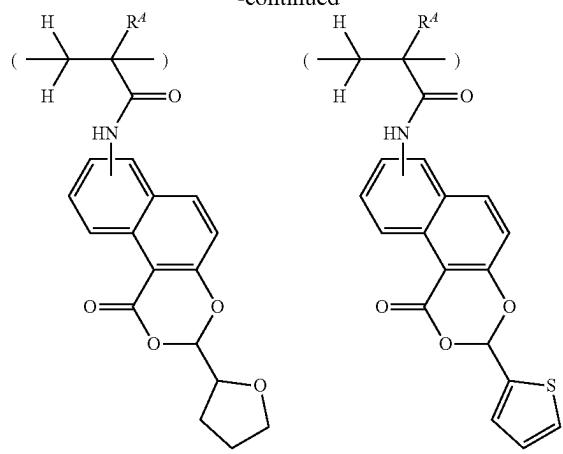
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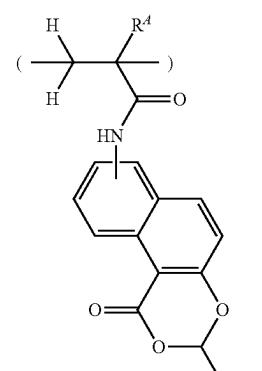
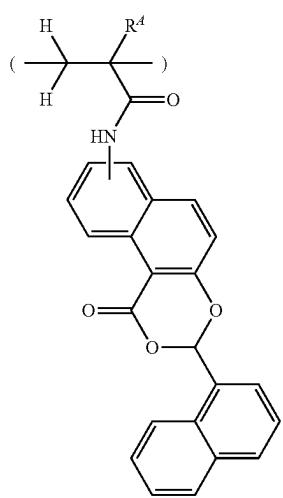
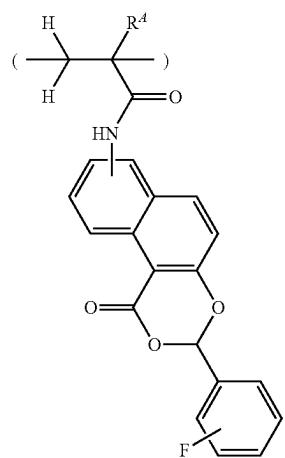
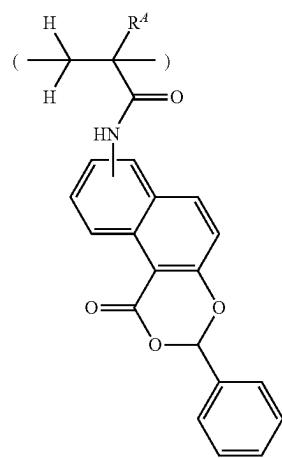
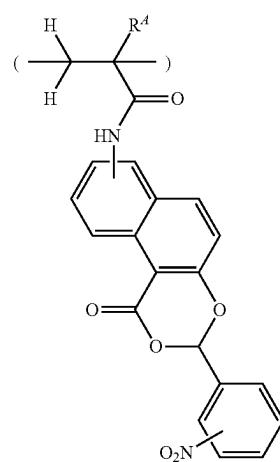
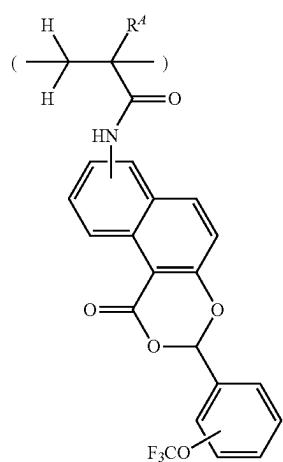
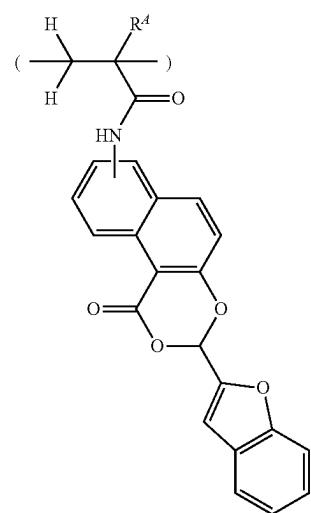
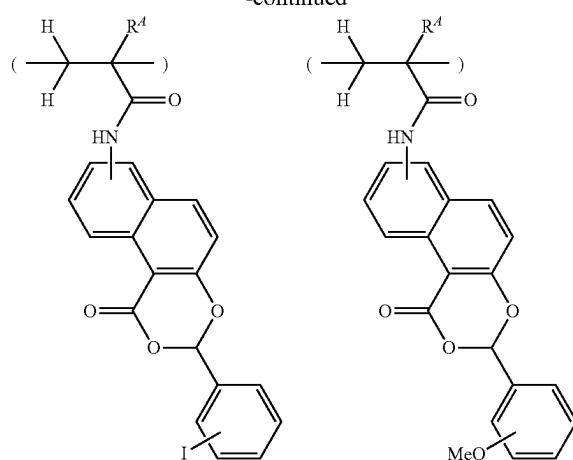
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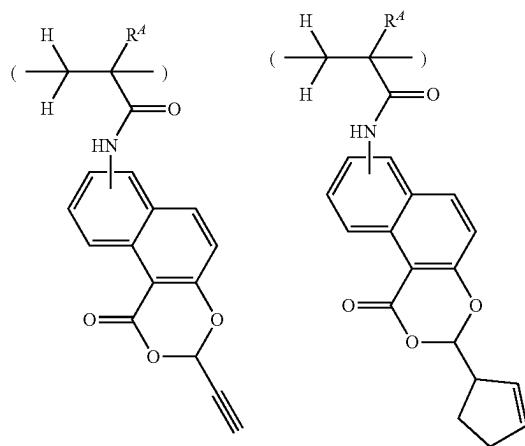
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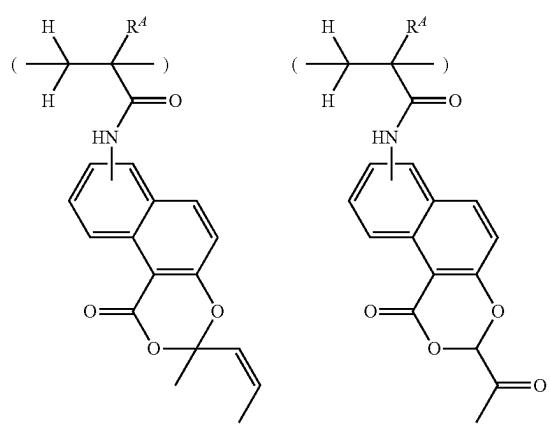
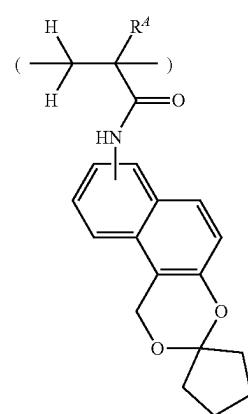
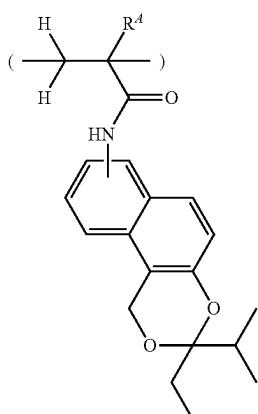
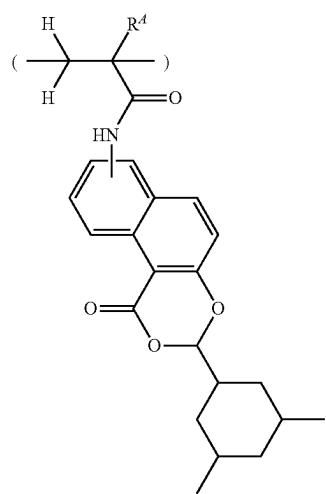
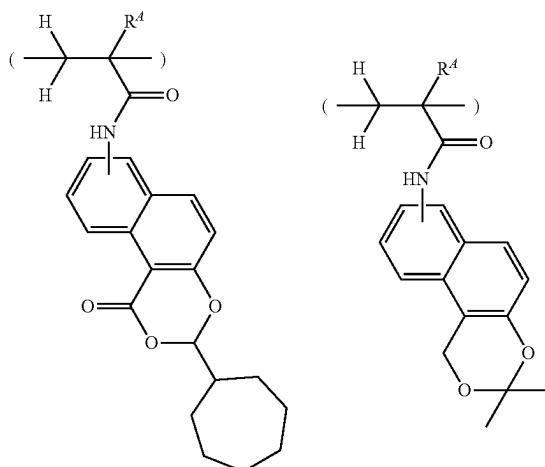
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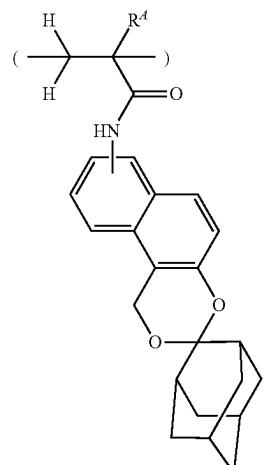
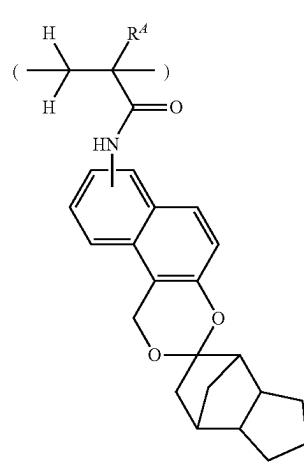
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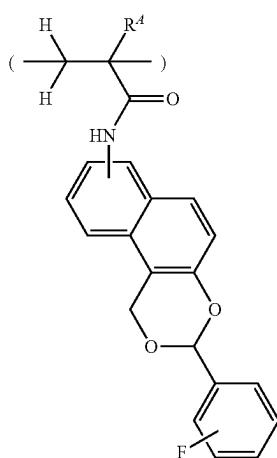
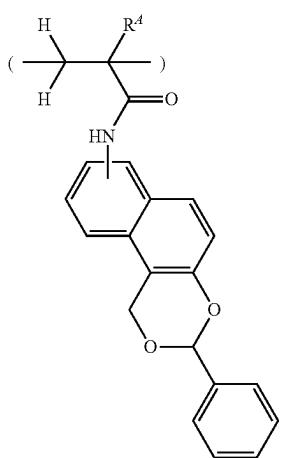
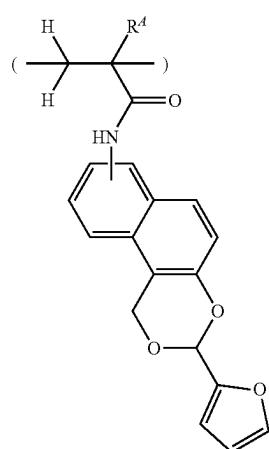
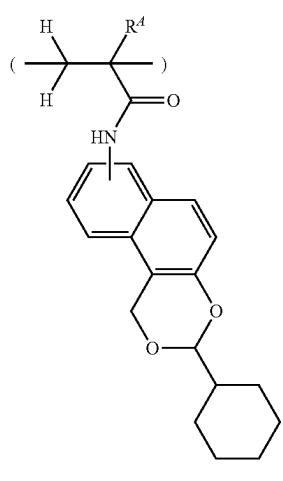
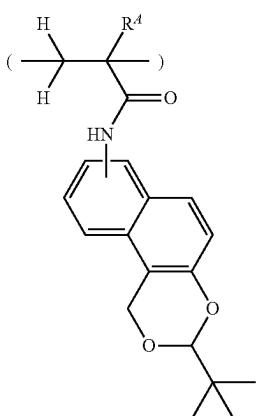
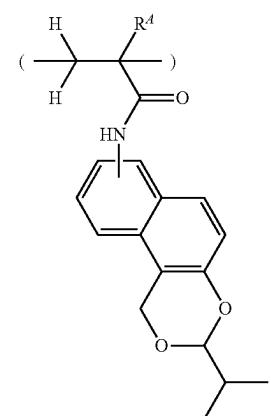
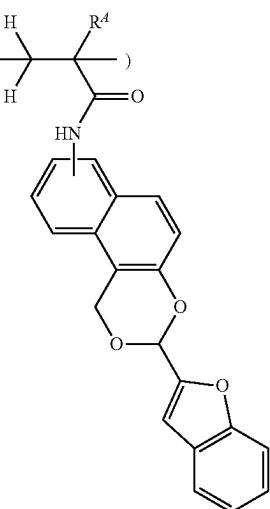
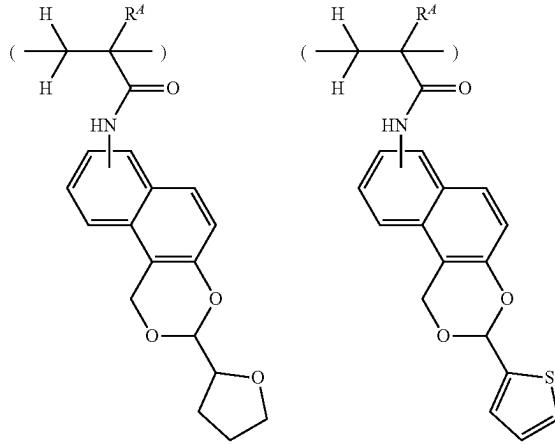
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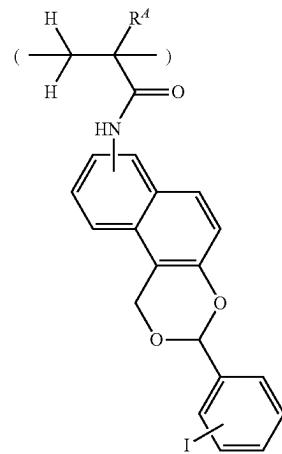
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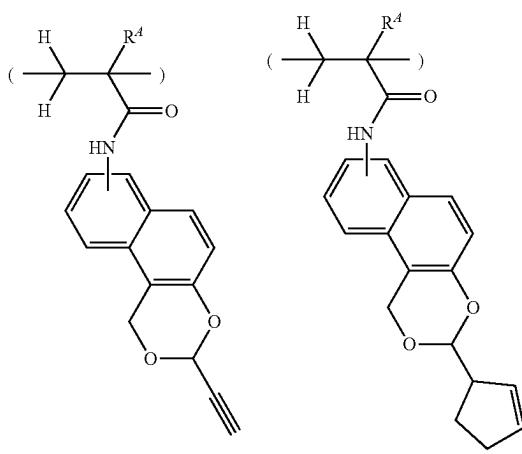
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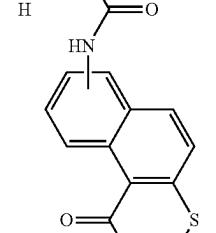
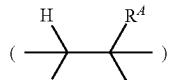
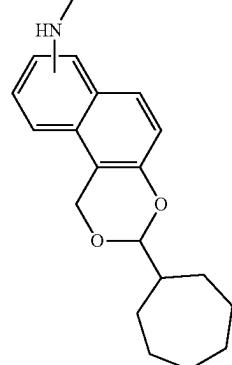
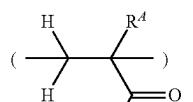
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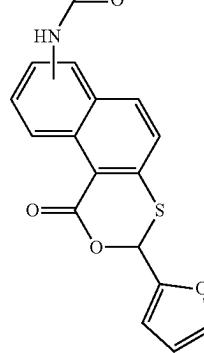
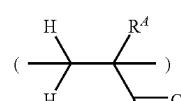
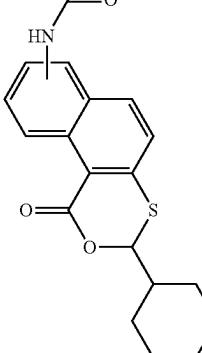
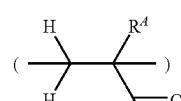
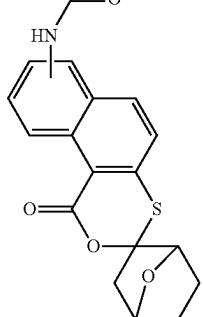
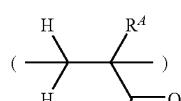
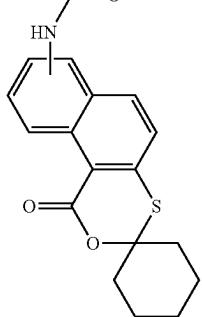
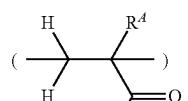
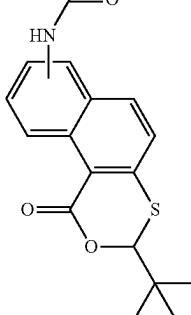
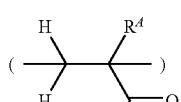
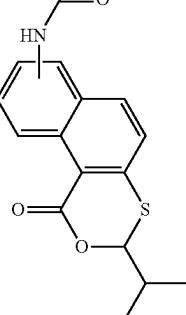
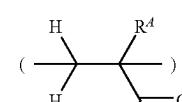
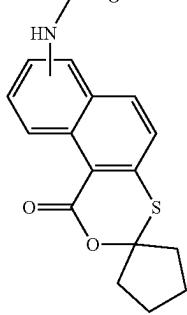
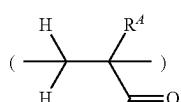
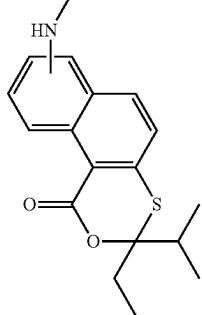
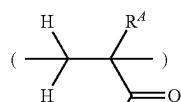
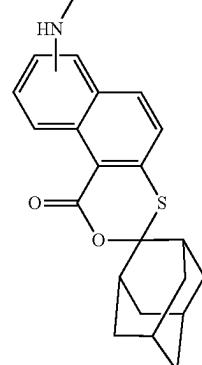
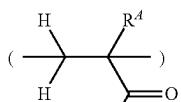
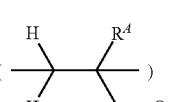
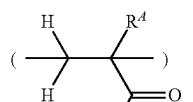
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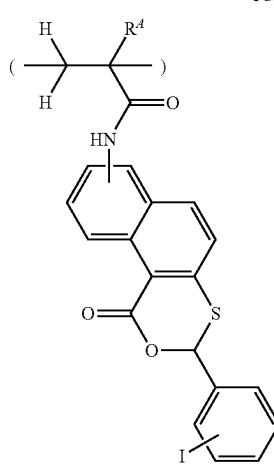
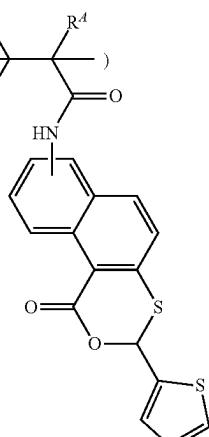
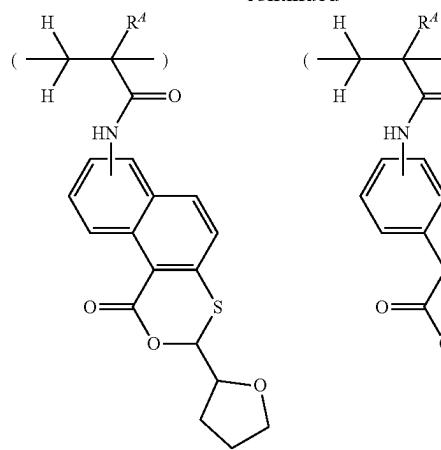
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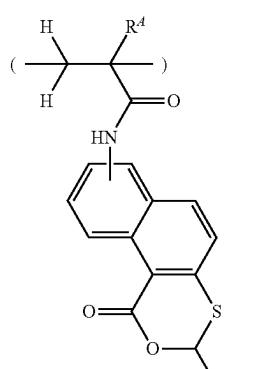
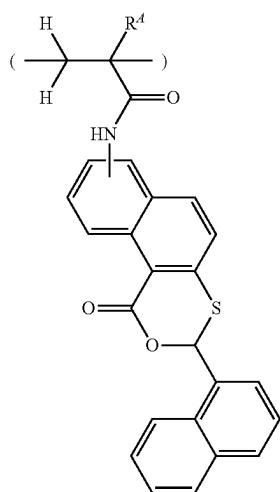
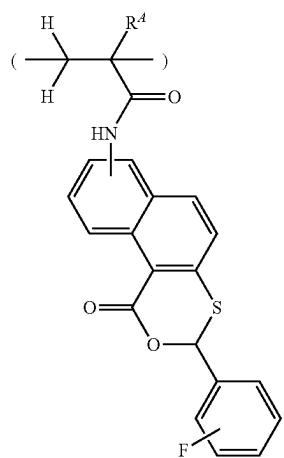
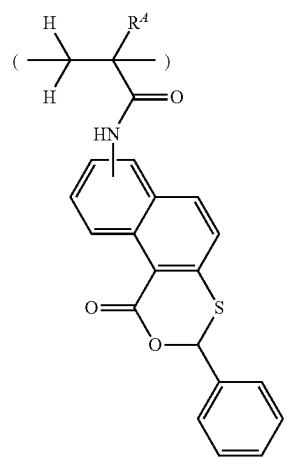
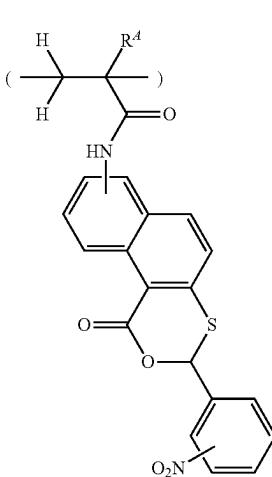
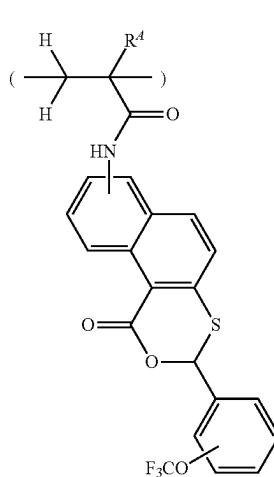
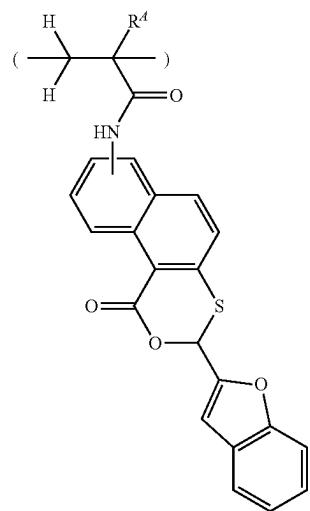
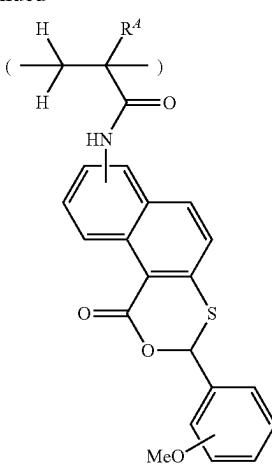
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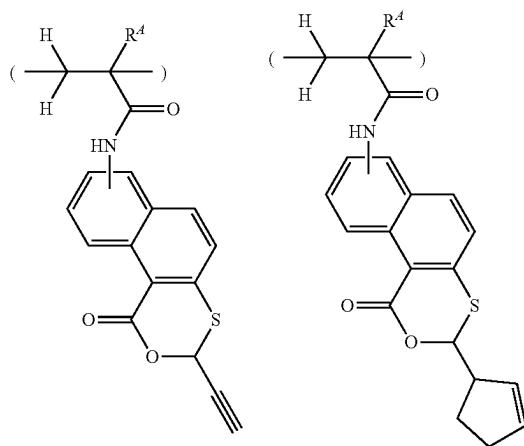
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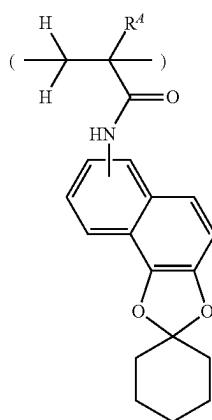
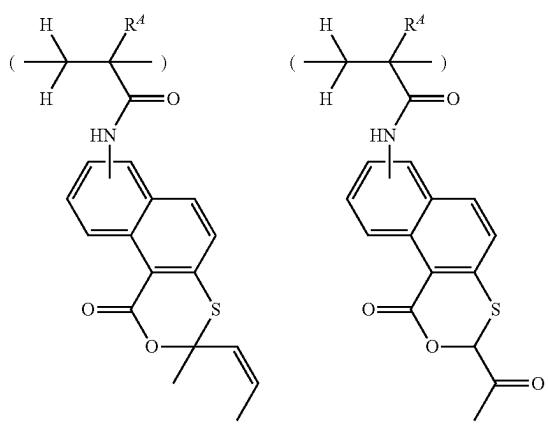
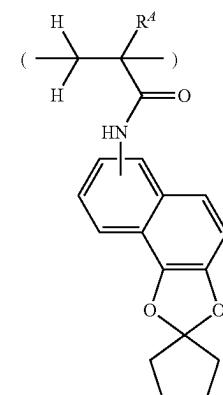
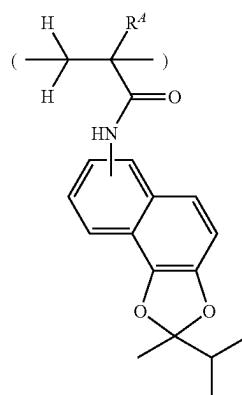
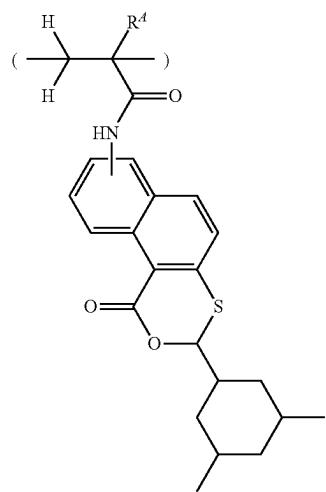
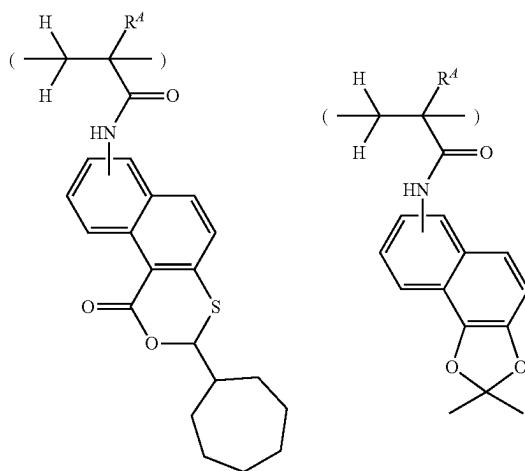
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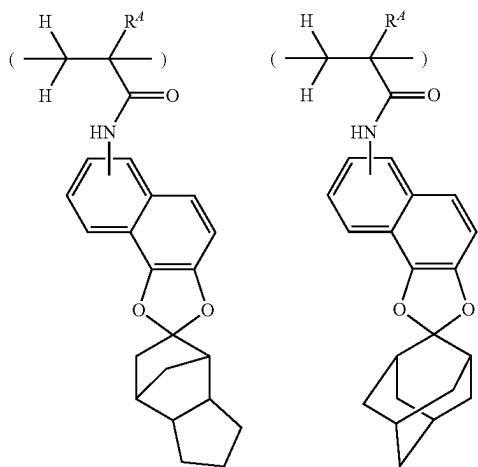
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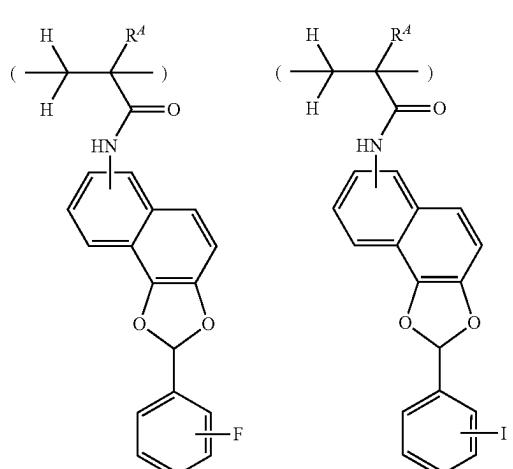
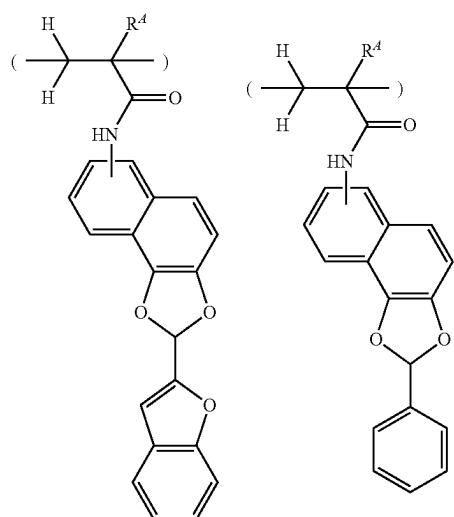
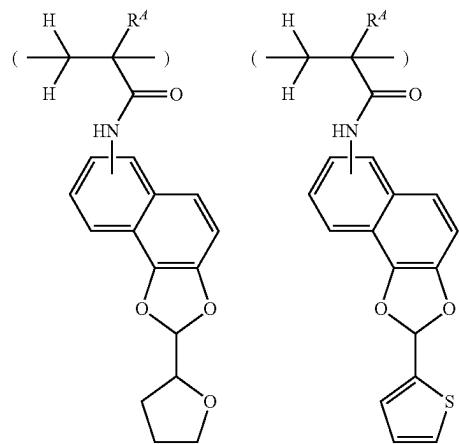
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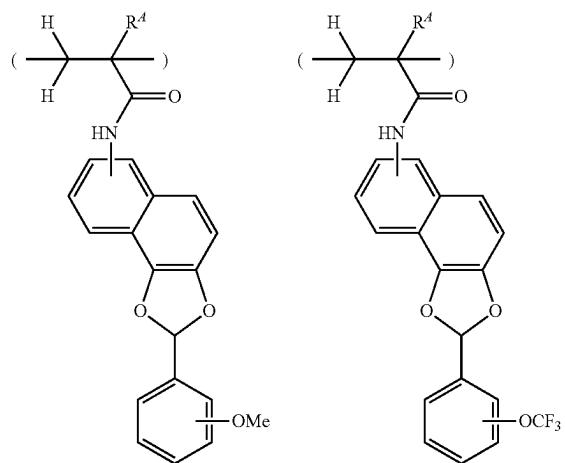
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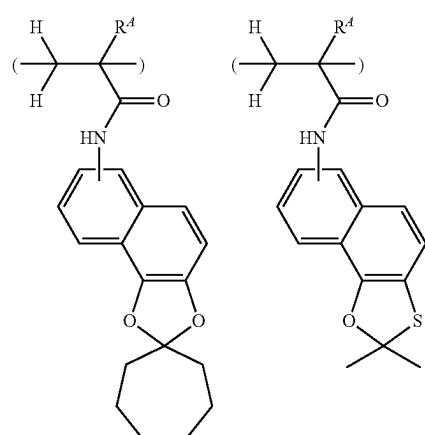
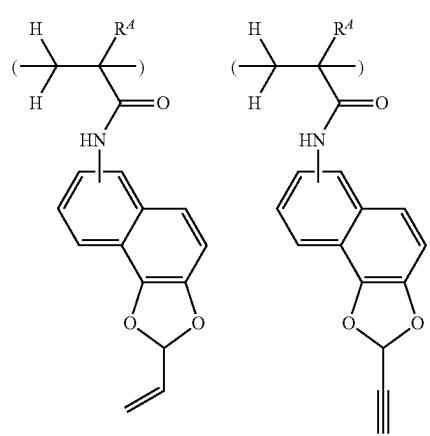
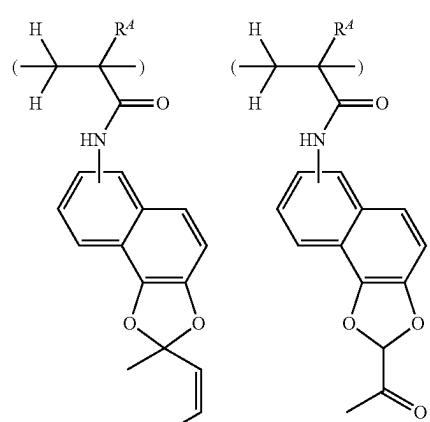
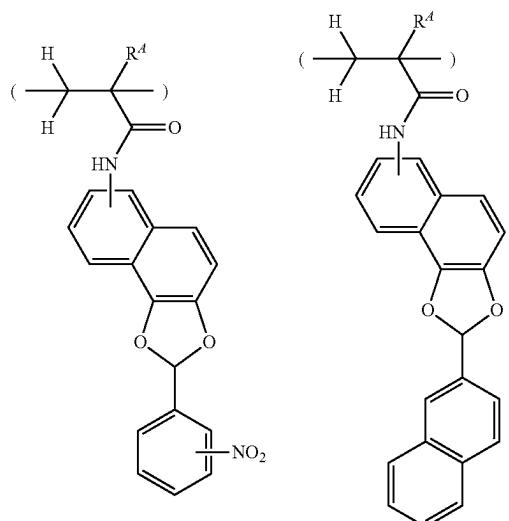
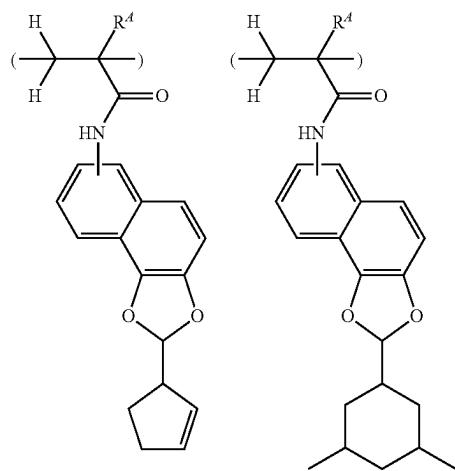
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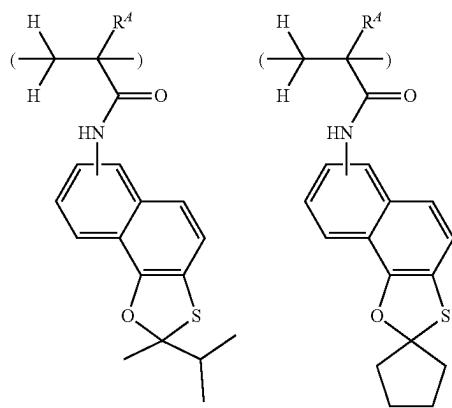
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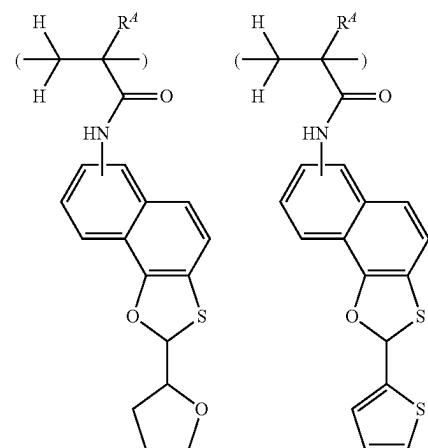
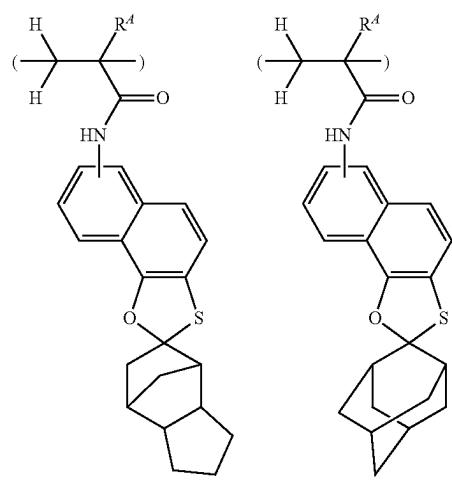
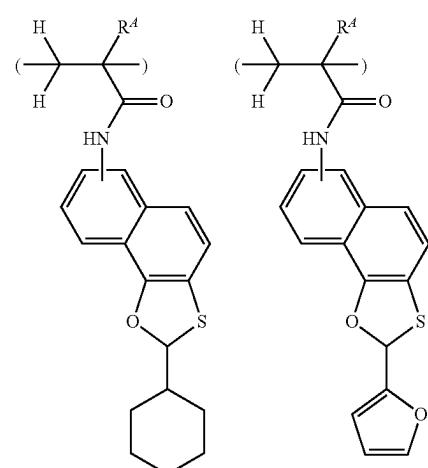
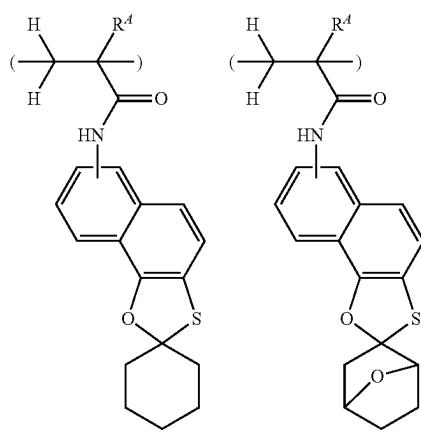
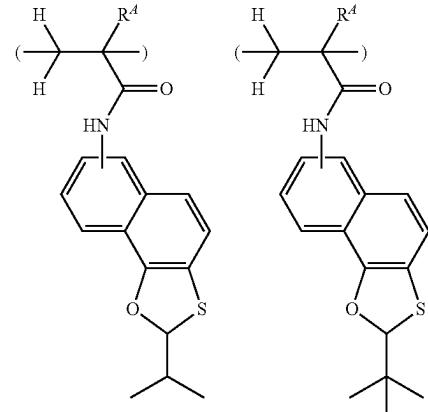
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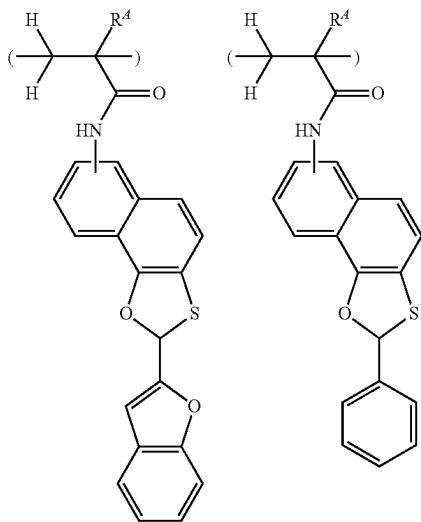
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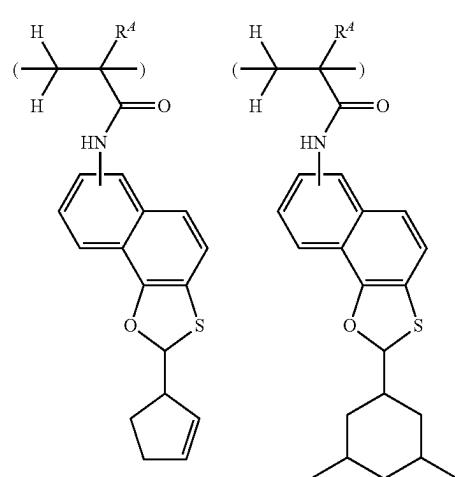
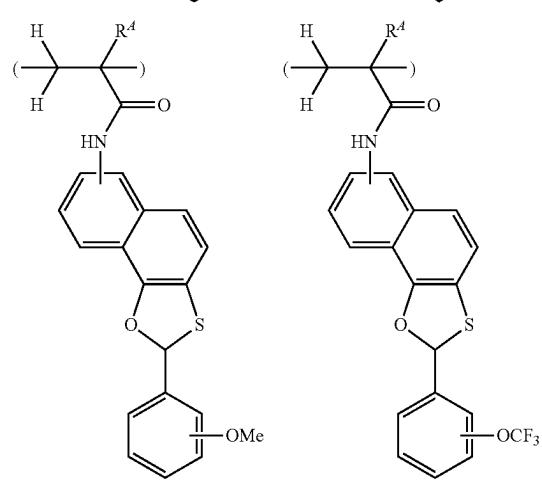
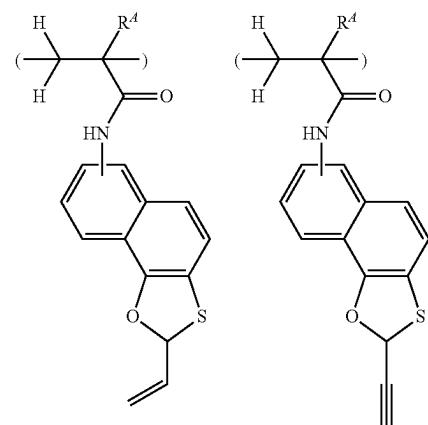
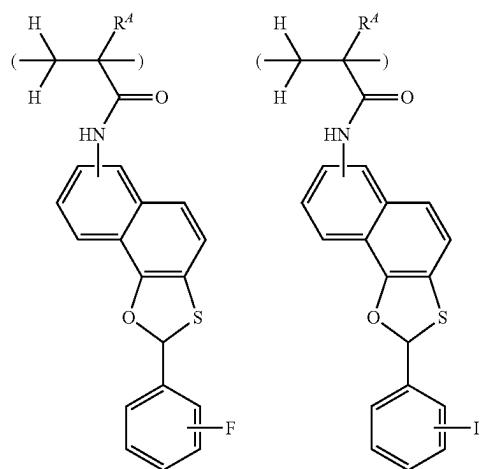
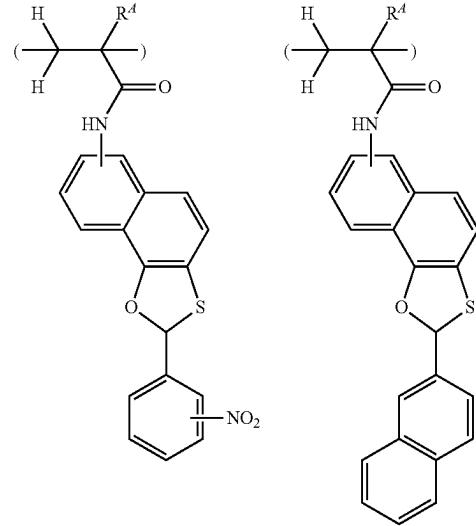
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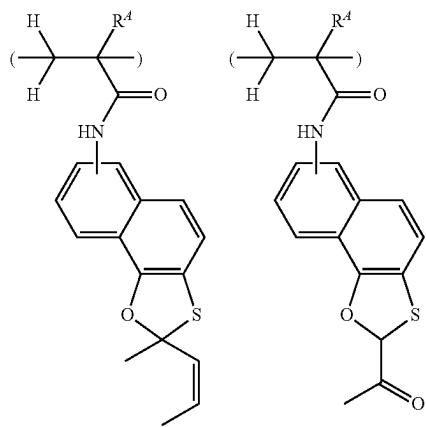
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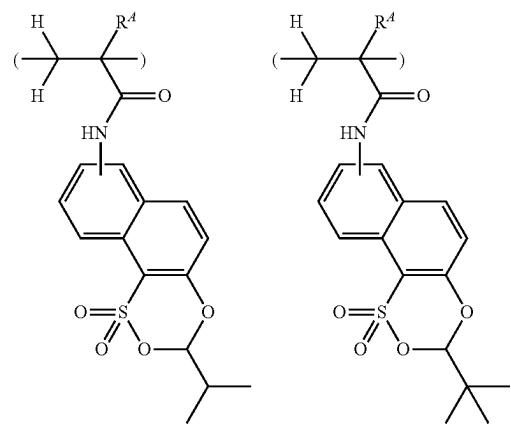
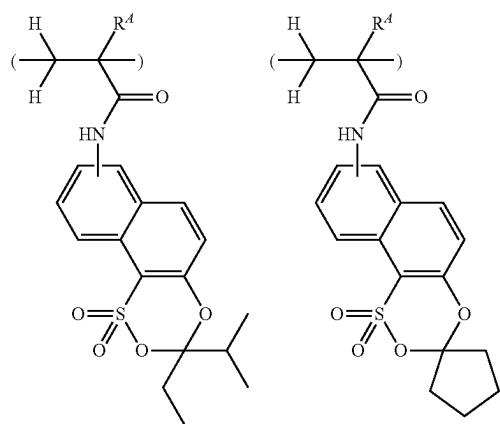
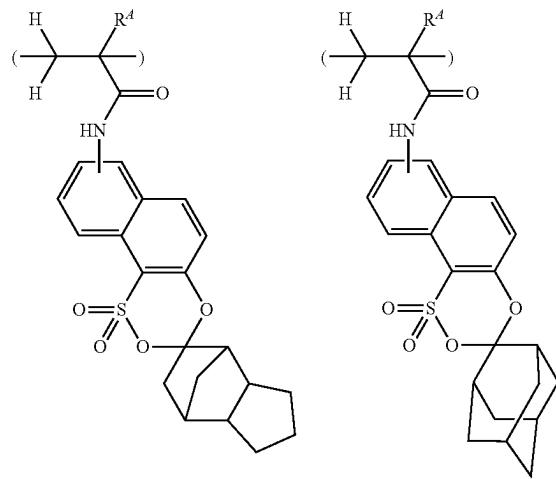
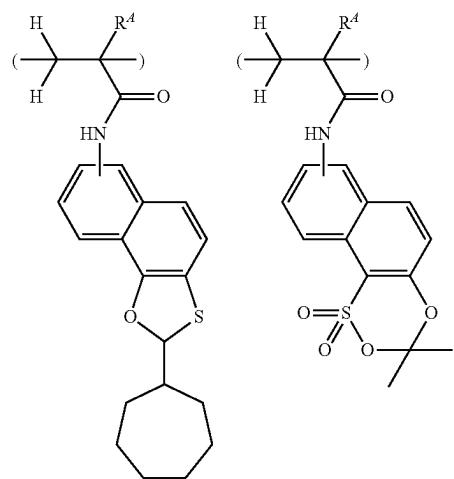
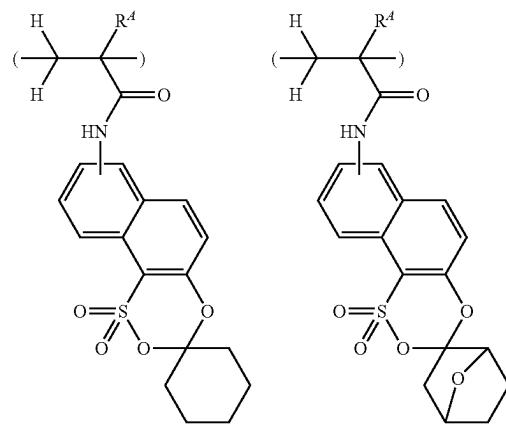
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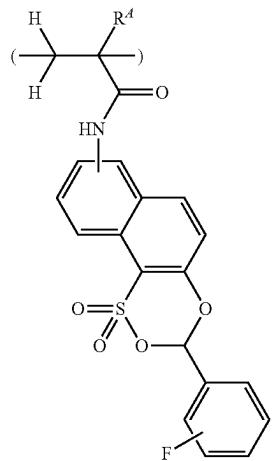
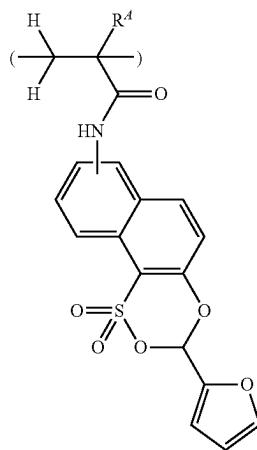
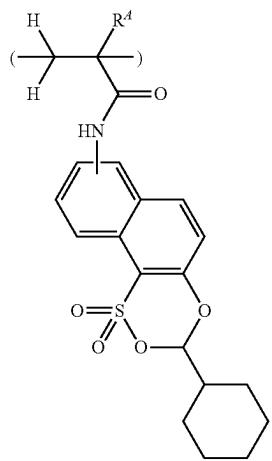
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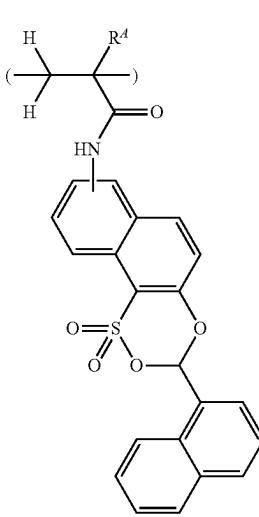
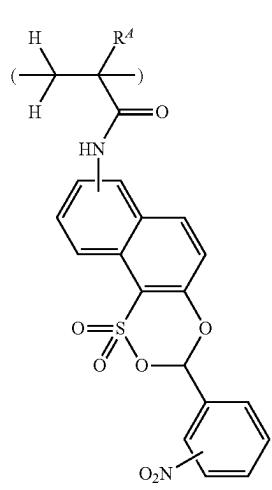
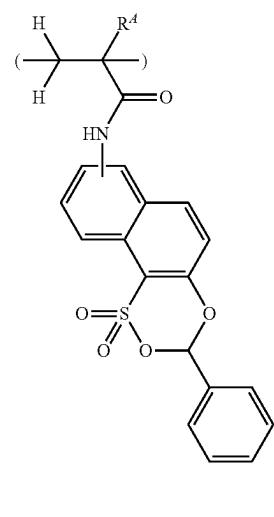
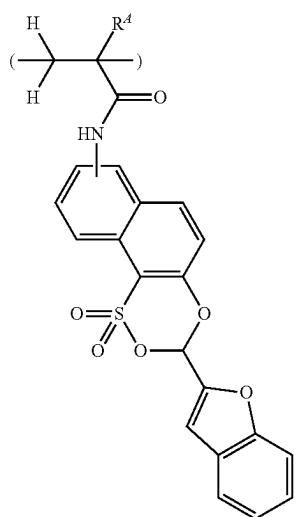
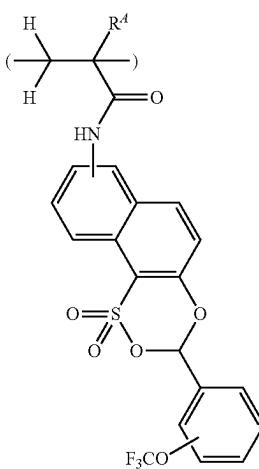
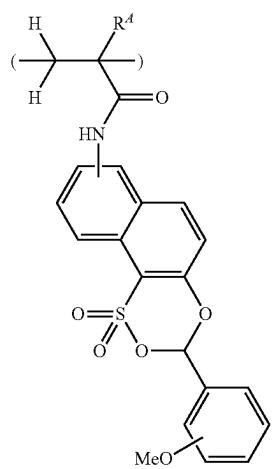
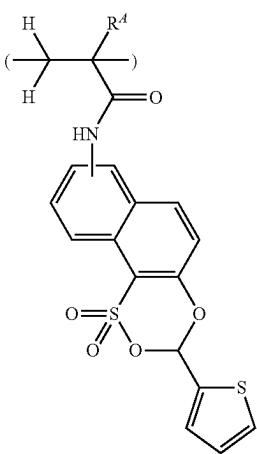
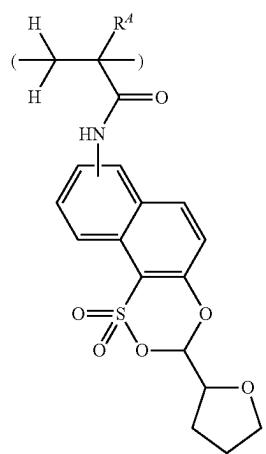
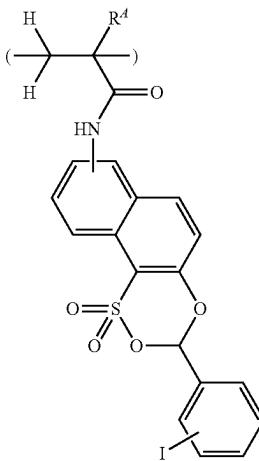
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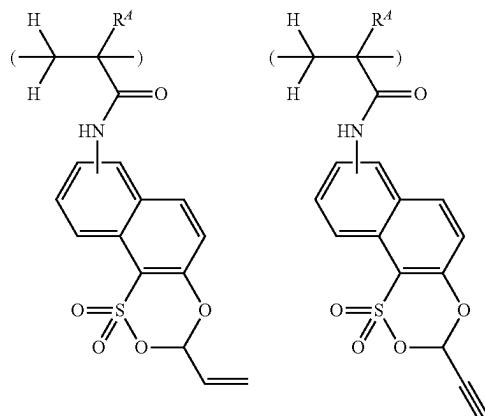
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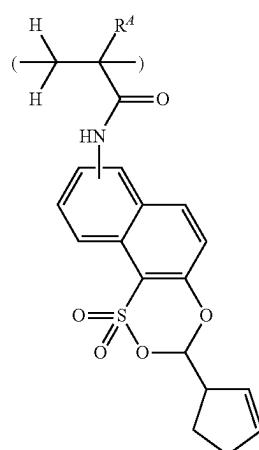
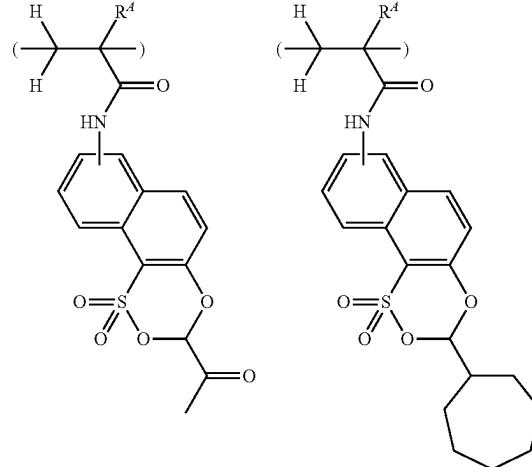
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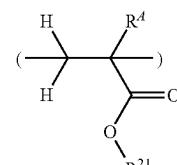
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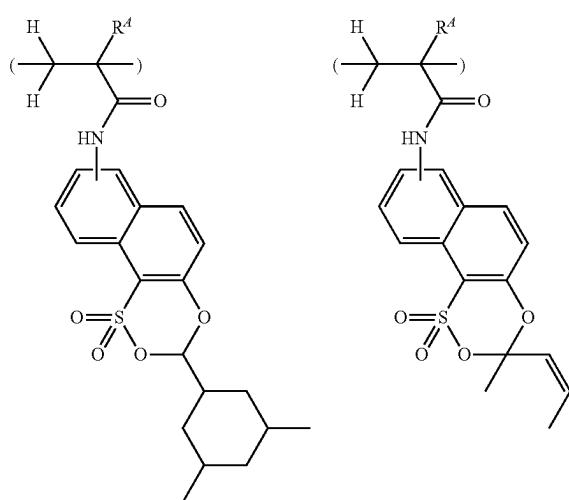
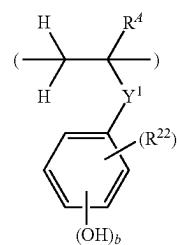
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(b1)



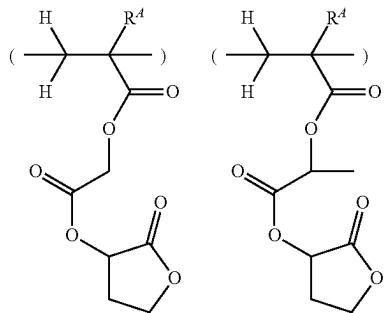
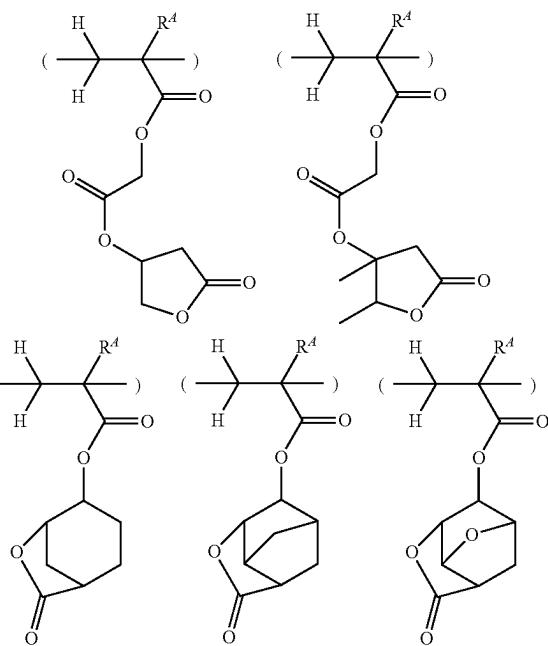
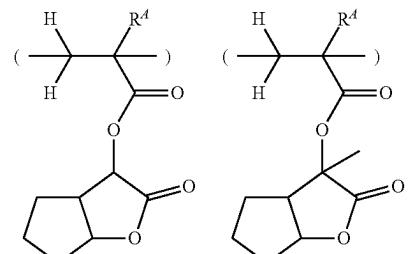
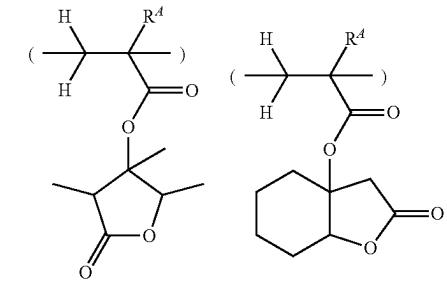
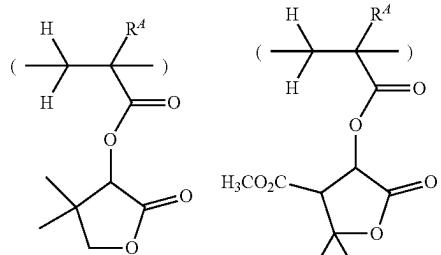
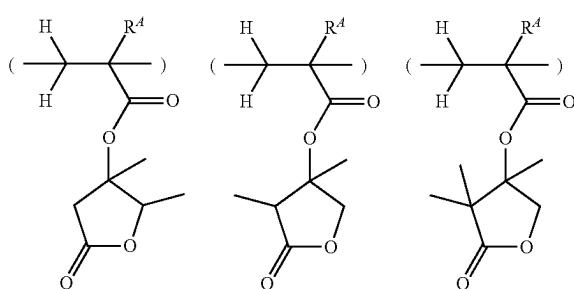
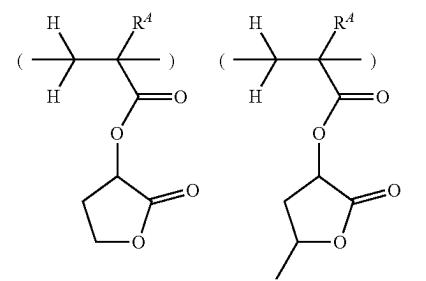
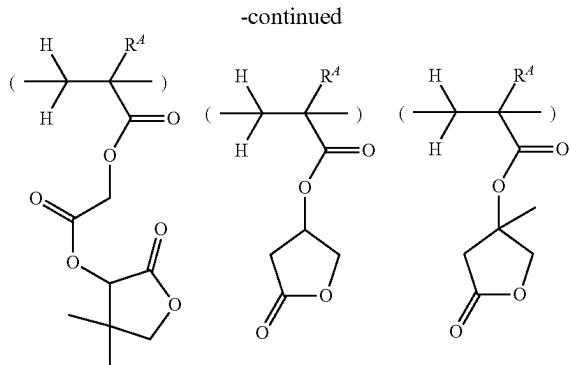
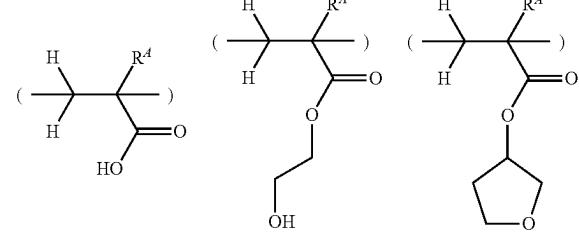
(b2)

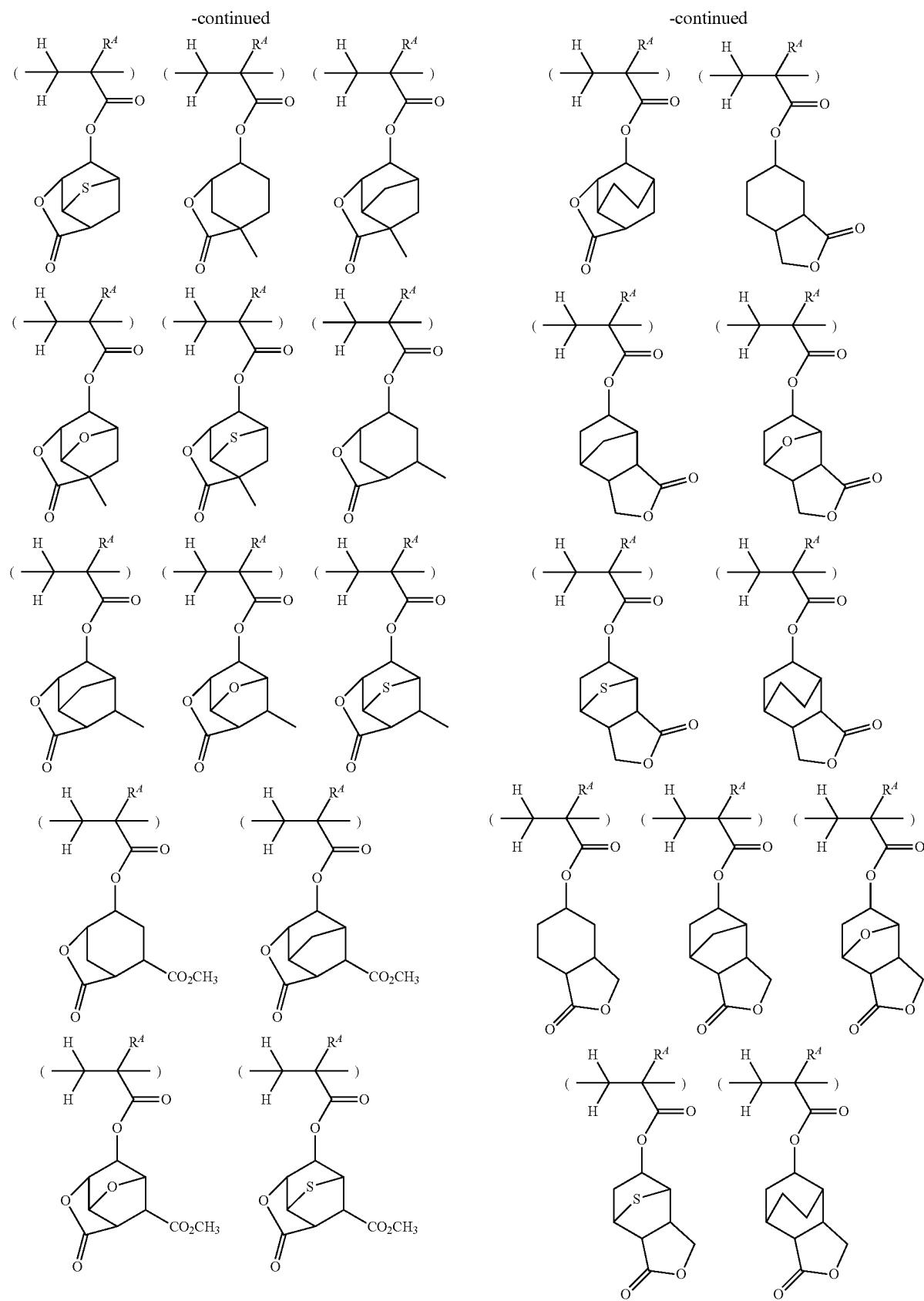


[0190] In a preferred embodiment, the base polymer further comprises repeat units having the formula (b1) or repeat units having the formula (b2), which are simply referred to as repeat units (b1) or (b2).

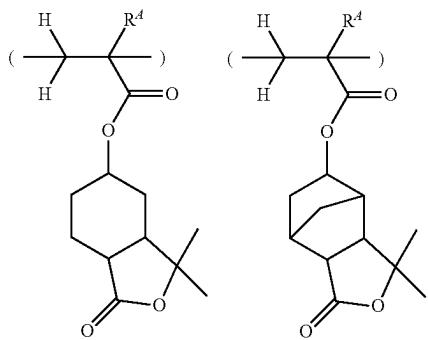
[0191] In formulae (b1) and (b2), R^A is each independently hydrogen, fluorine, methyl or trifluoromethyl. Y^1 is a single bond or $*-C(=O)-O-$ wherein $*$ designates a point of attachment to the carbon atom in the backbone. R^{21} is hydrogen or a C_1-C_{20} group containing at least one structure selected from among hydroxy other than phenolic hydroxy, cyano, carbonyl, carboxy, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring and carboxylic anhydride ($-C(=O)-O-C(=O)-$). R^{22} is halogen, hydroxy, carboxy, nitro, cyano, a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, C_1-C_{20} hydrocarbylcarbonyl group which may contain a heteroatom, C_2-C_{20} hydrocarbylcarbonyloxy group which may contain a heteroatom or C_2-C_{20} hydrocarbyloxycarbonyl group which may contain a heteroatom. The subscript b is an integer of 1 to 4, c is an integer of 0 to 4, and $b+c$ is from 1 to 5.

[0192] Examples of the repeat unit (b1) are shown below, but not limited thereto. Herein, R^A is as defined above.

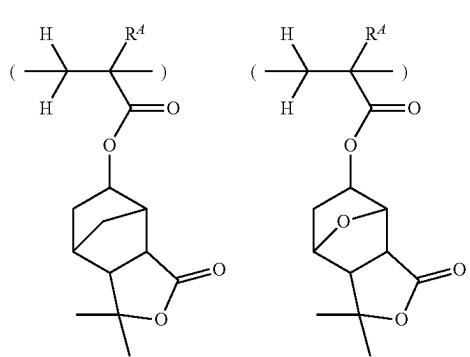
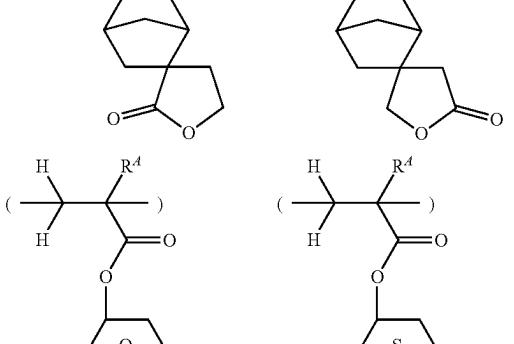
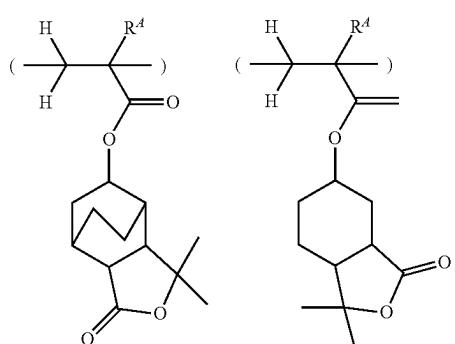
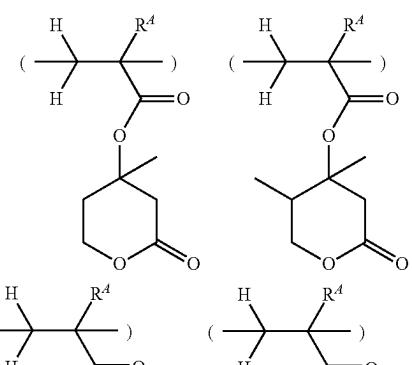
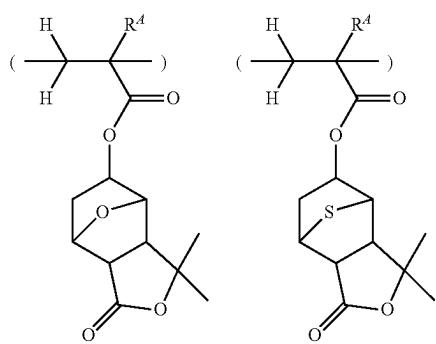
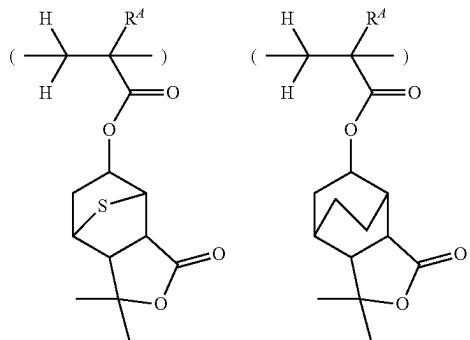


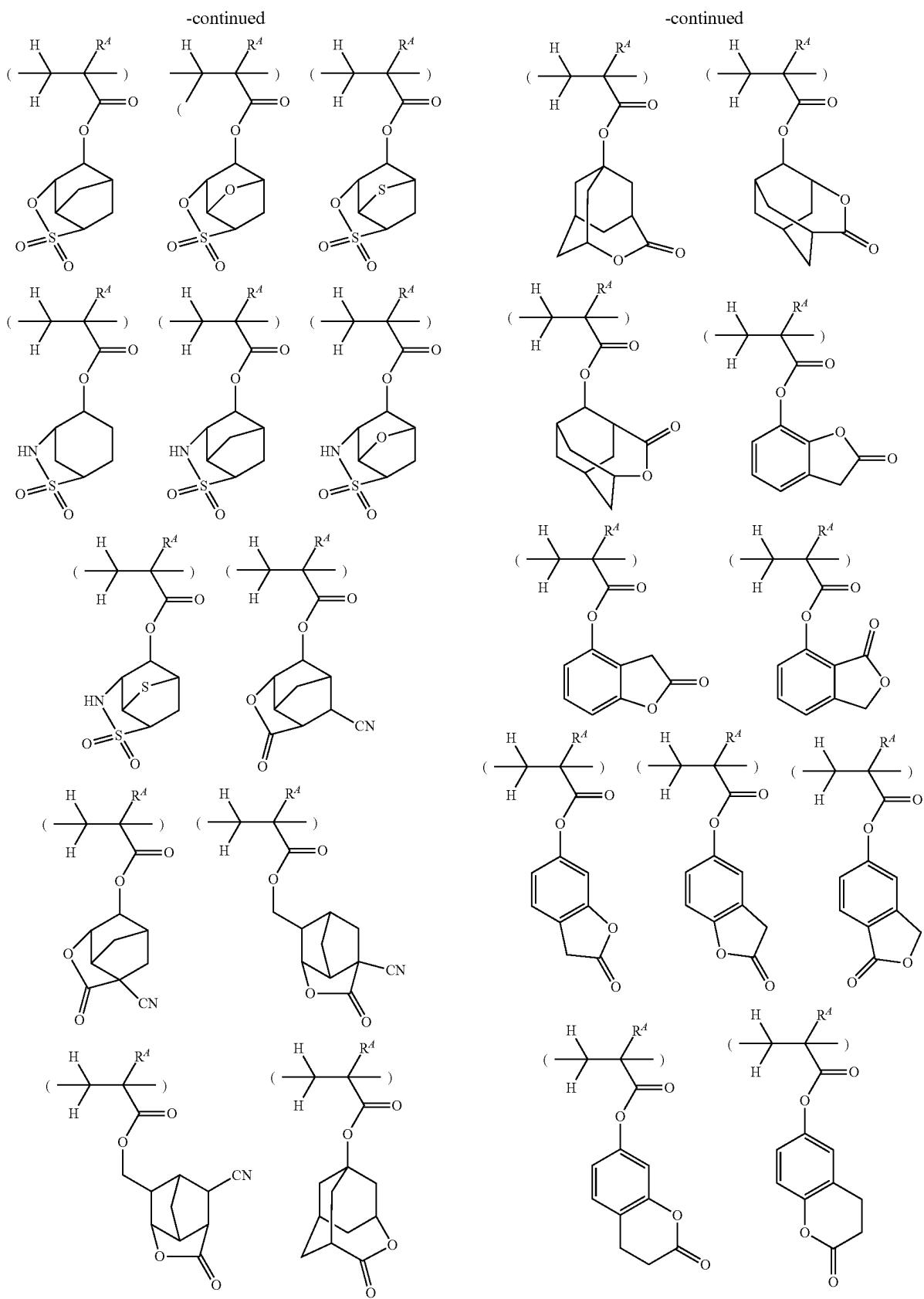


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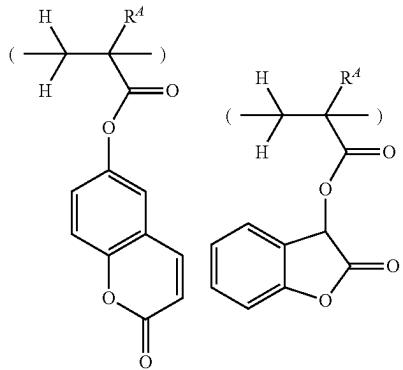


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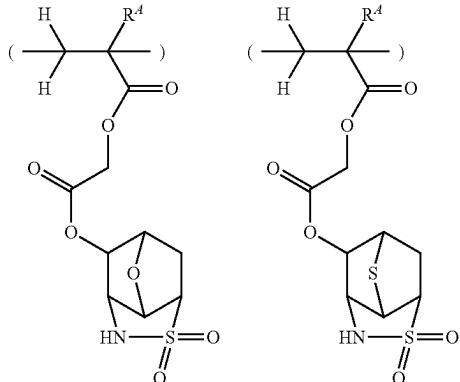
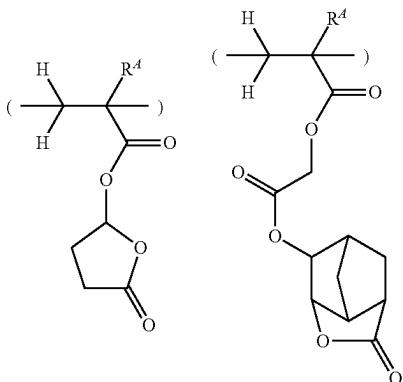
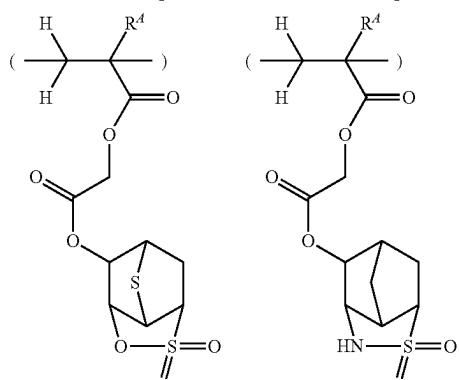
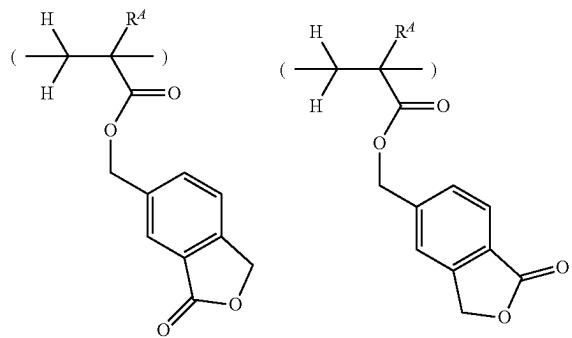
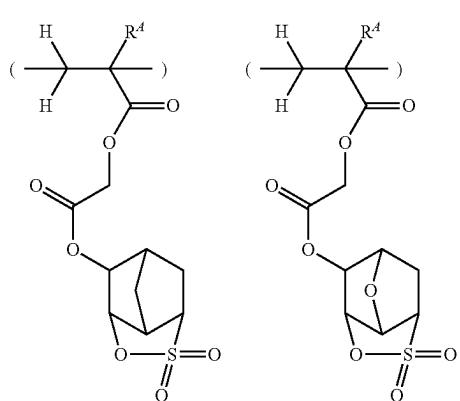
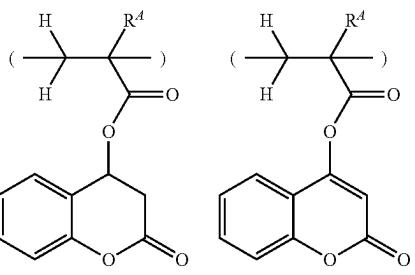
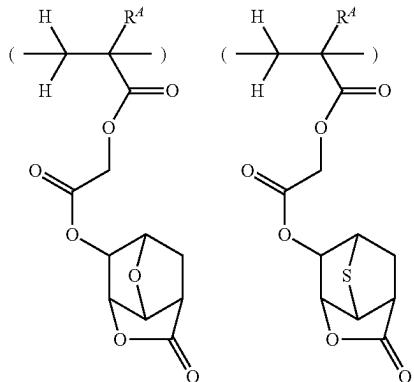




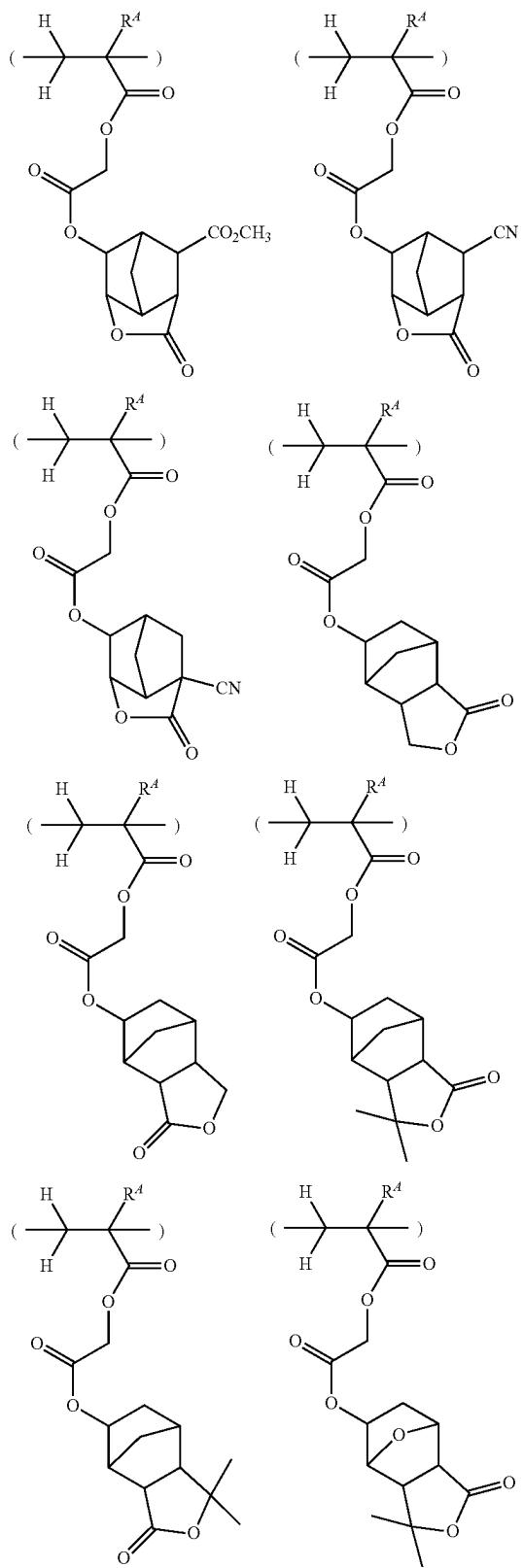
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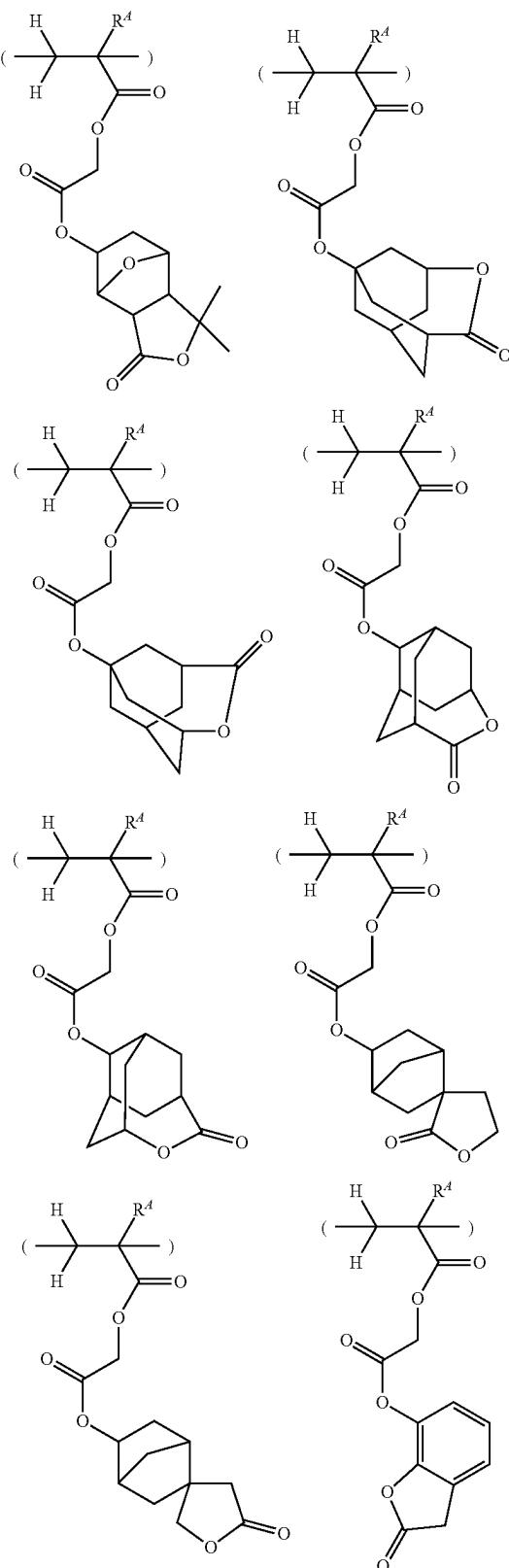
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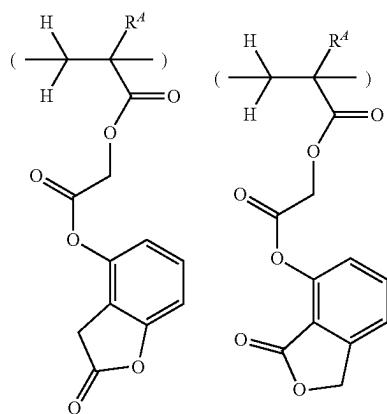
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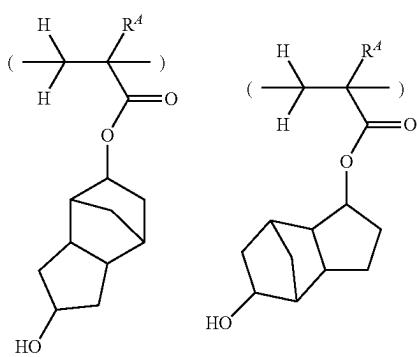
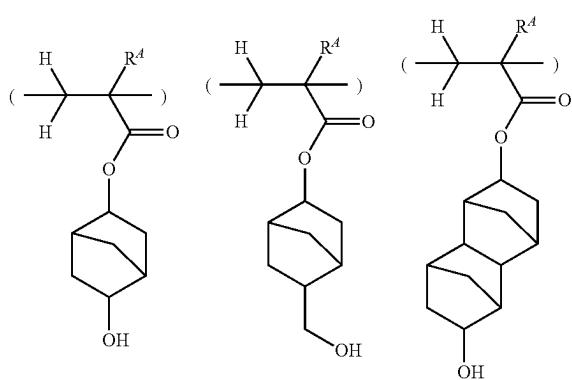
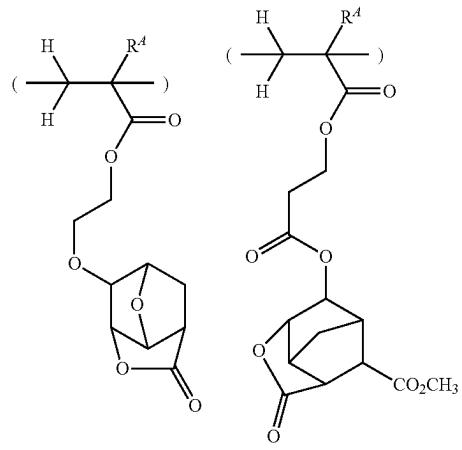
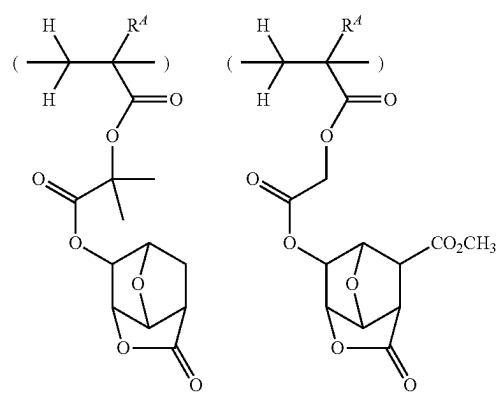
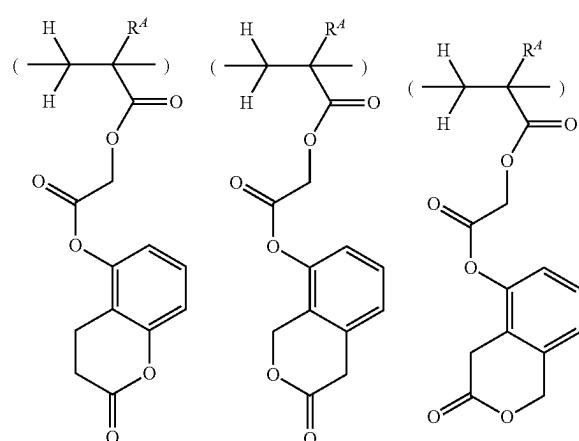
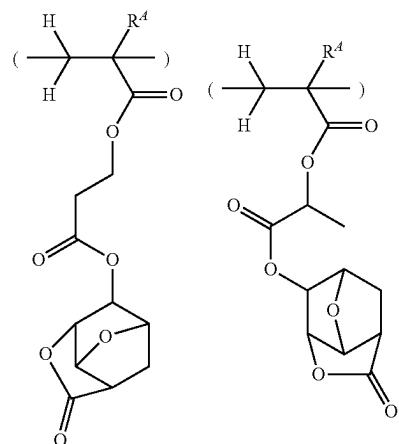
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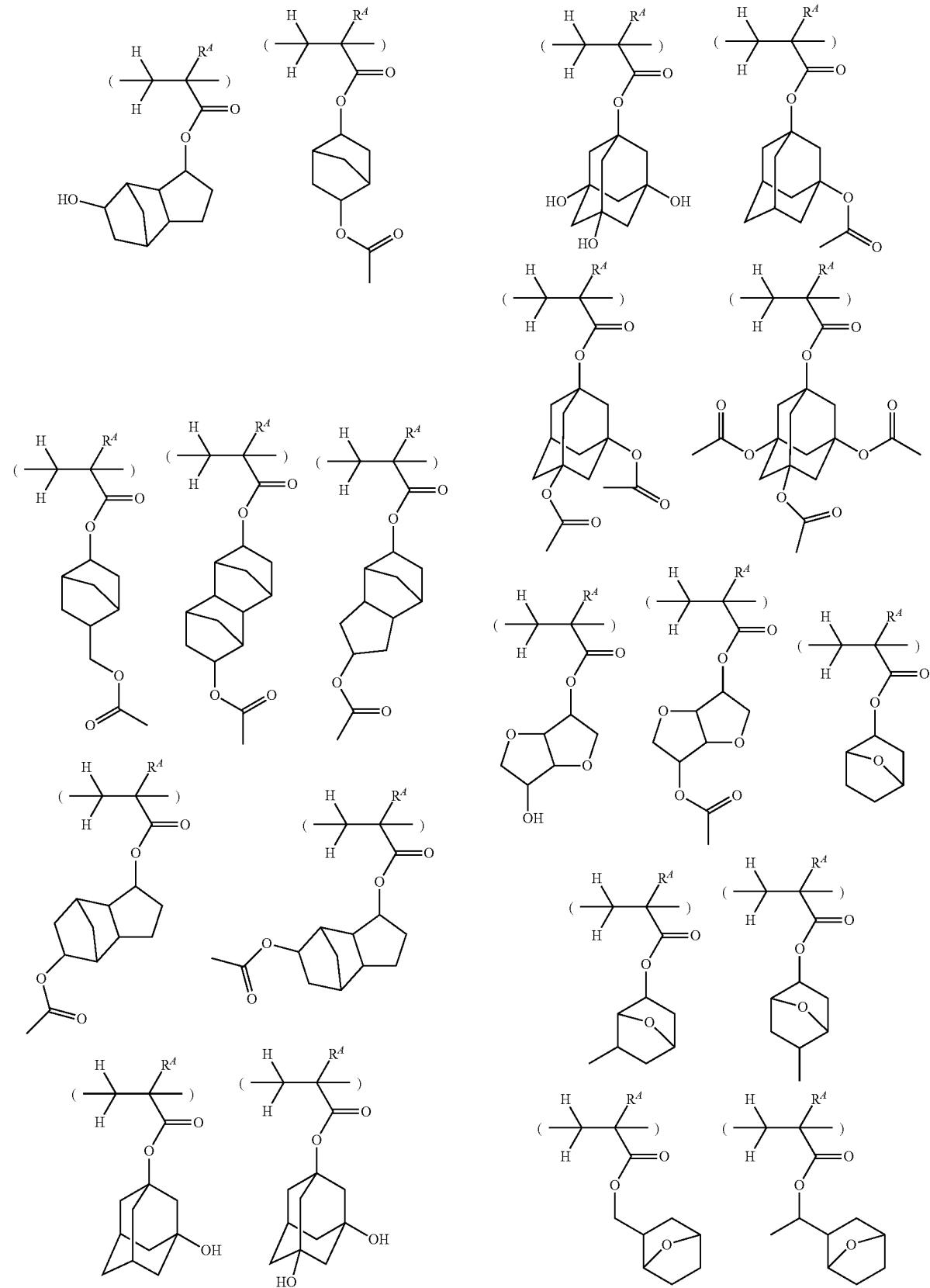
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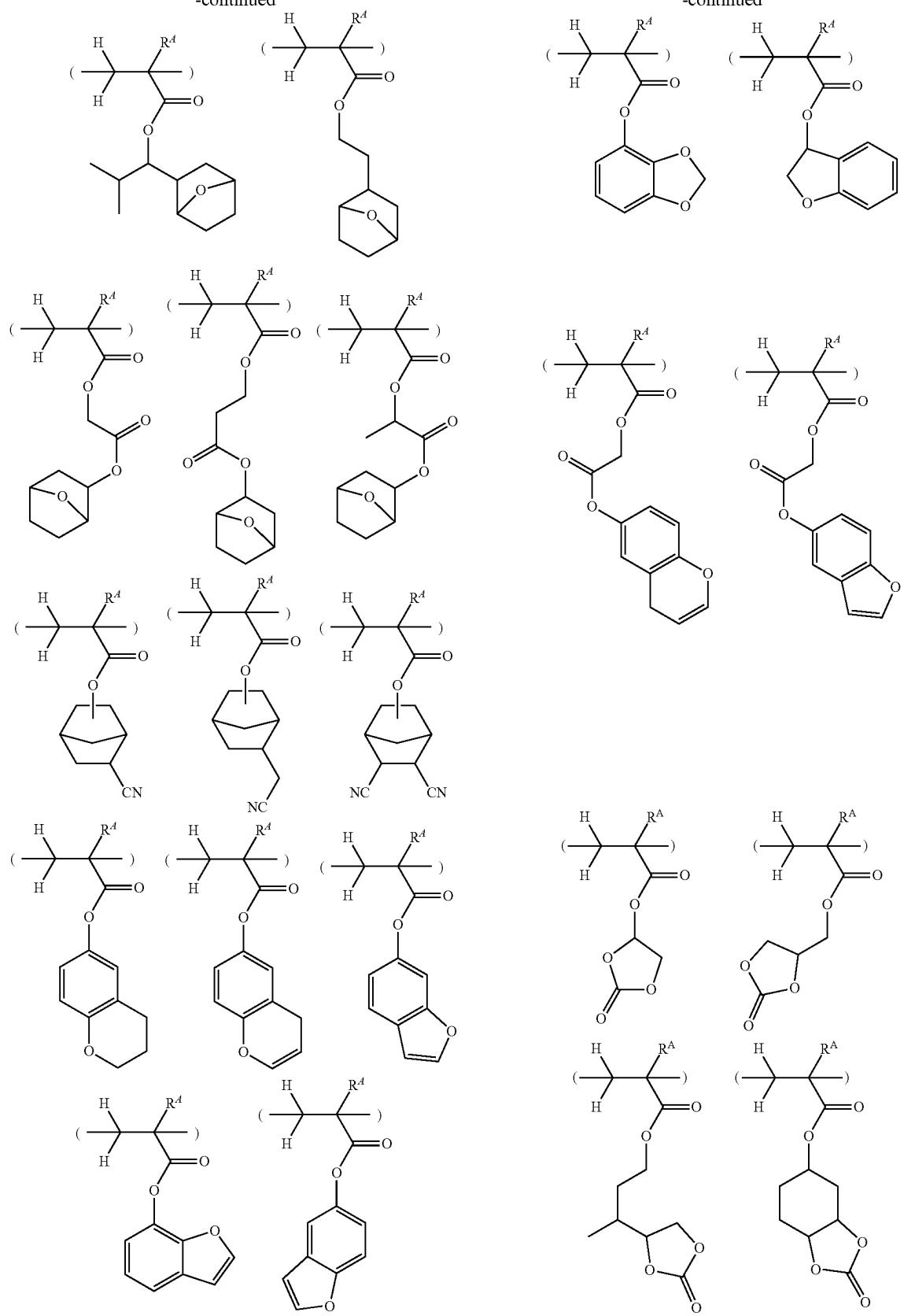
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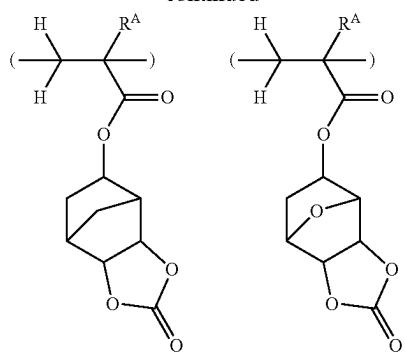
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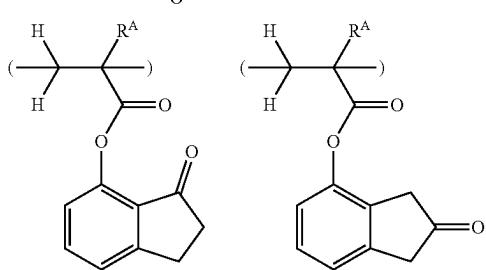
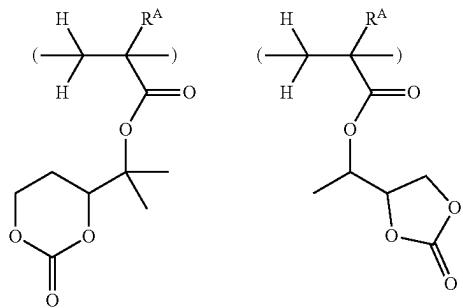
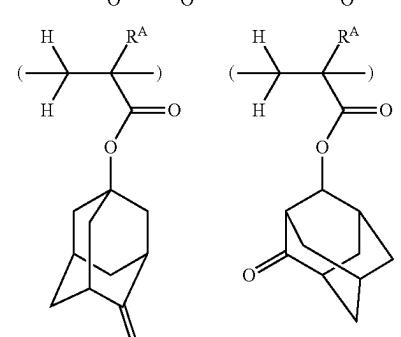
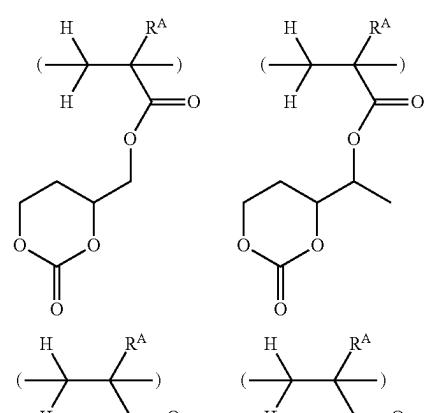
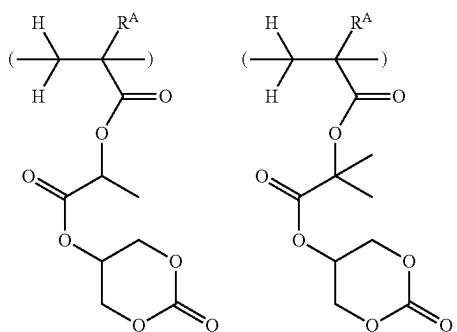
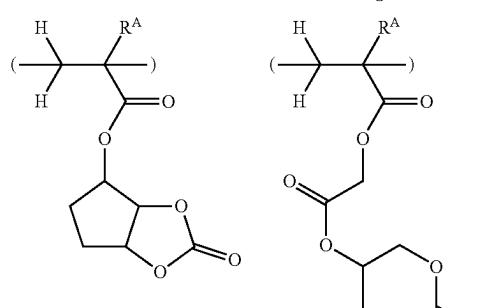
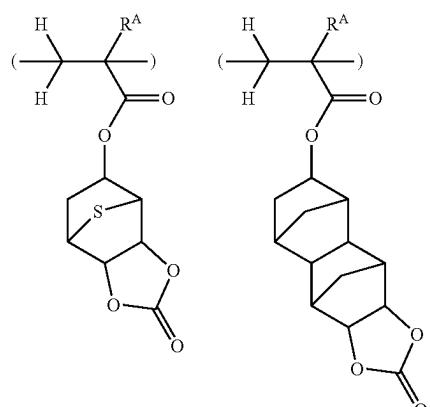
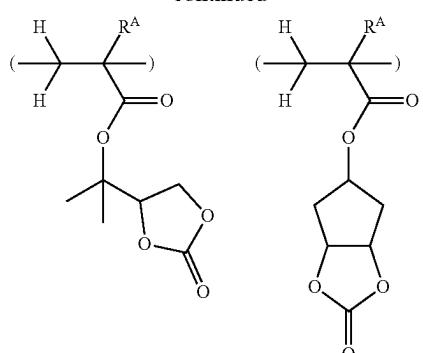
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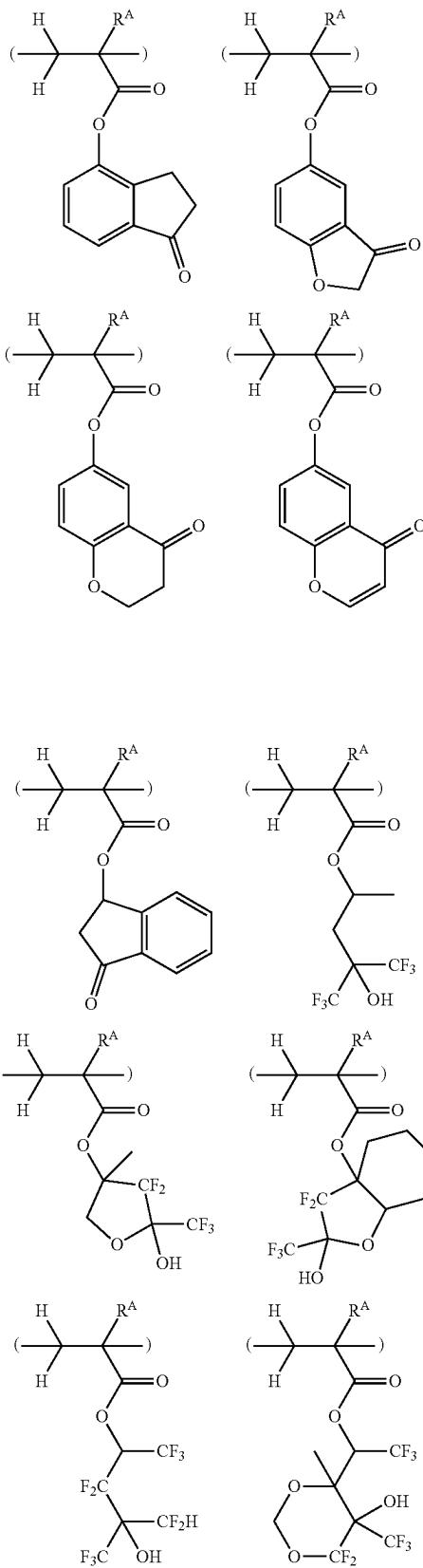
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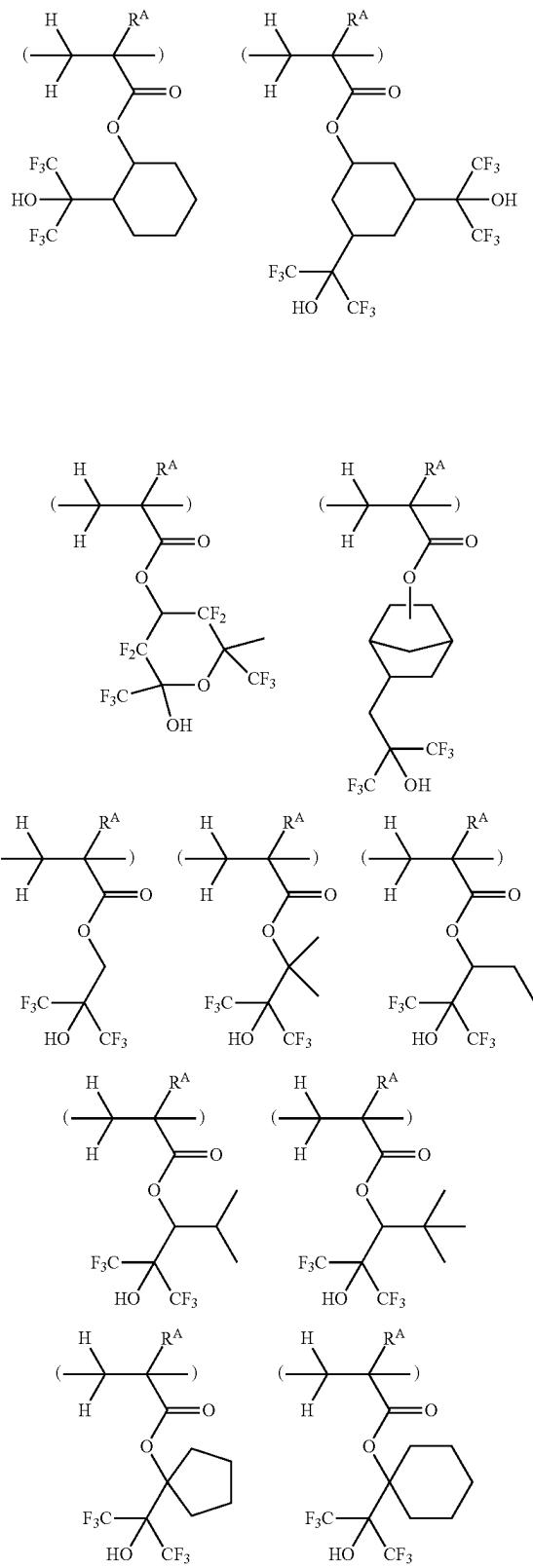
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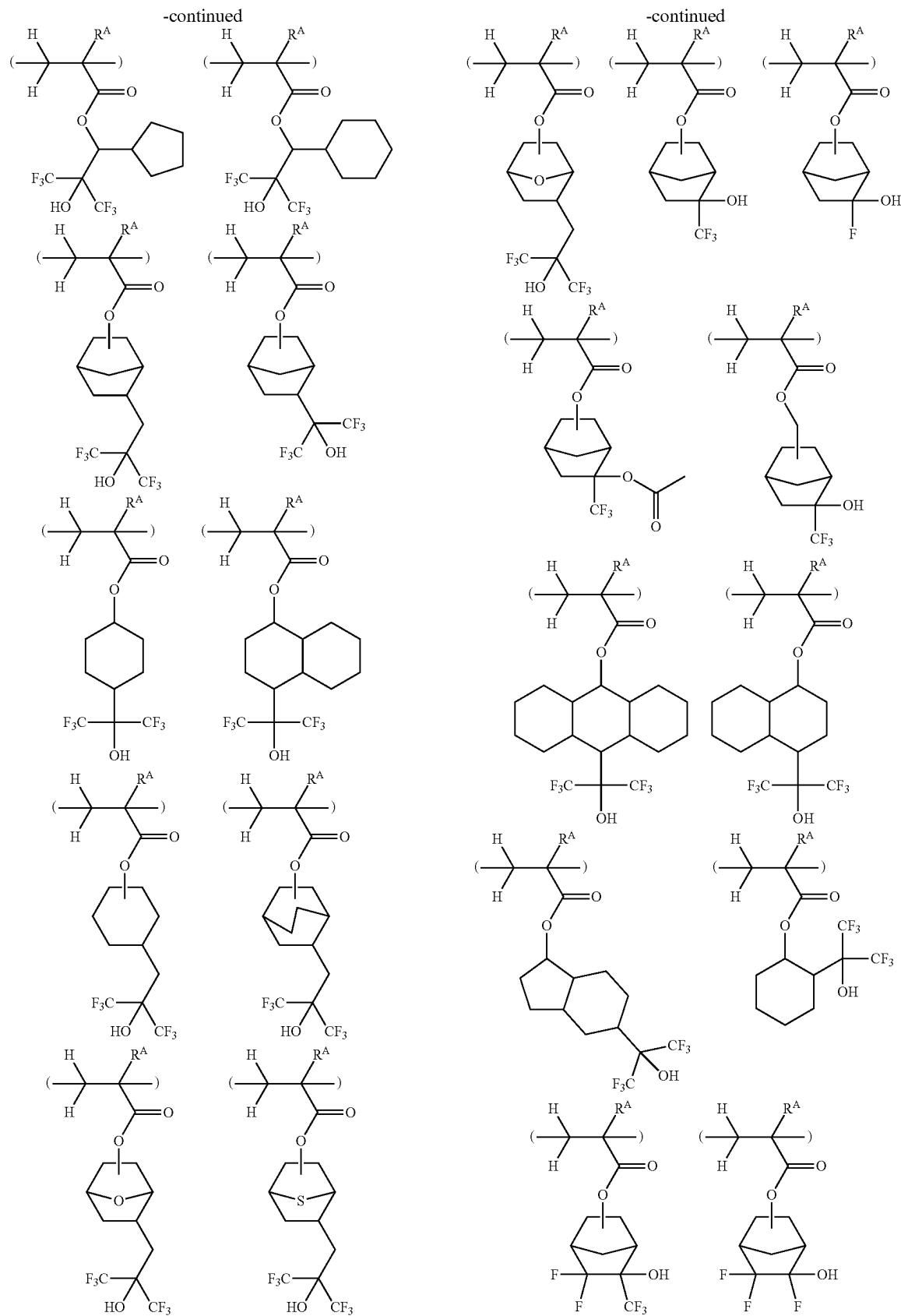


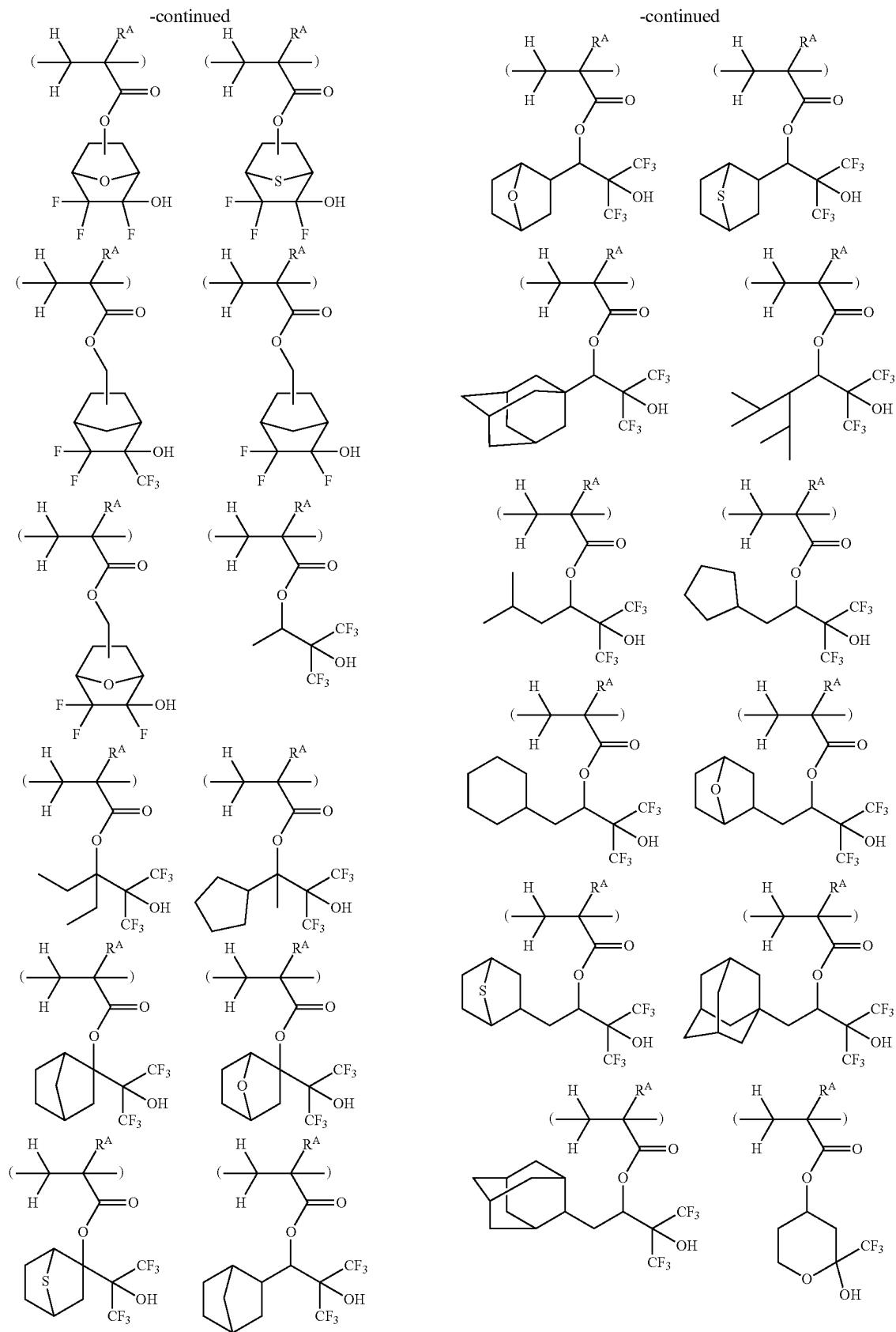
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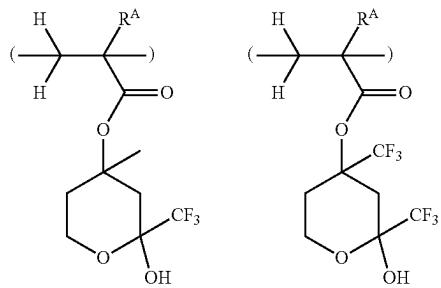
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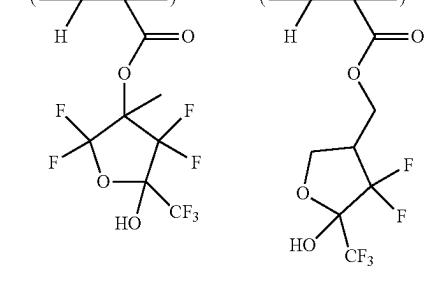
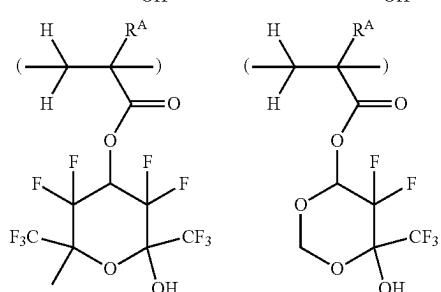
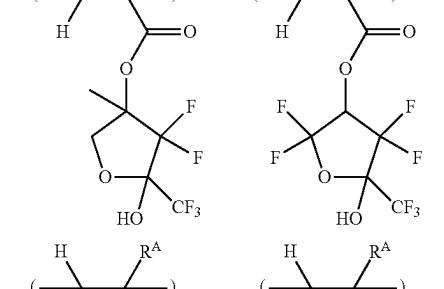
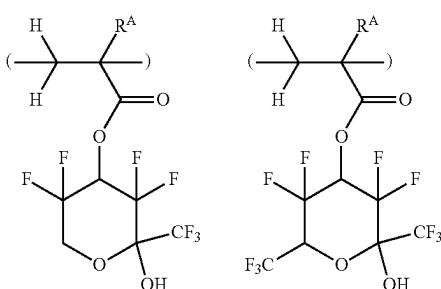
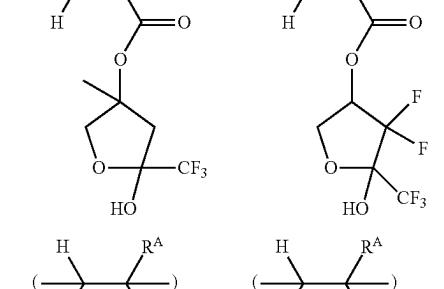
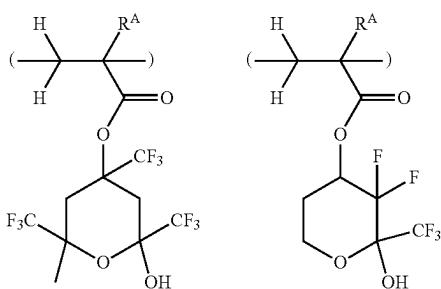
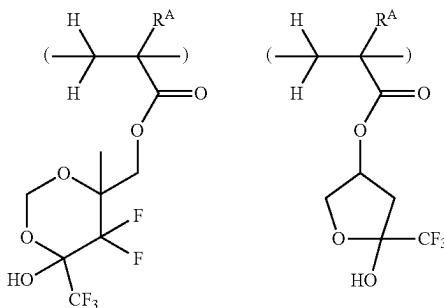
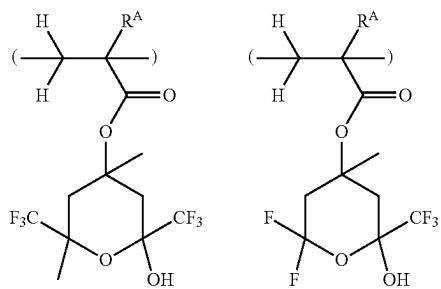
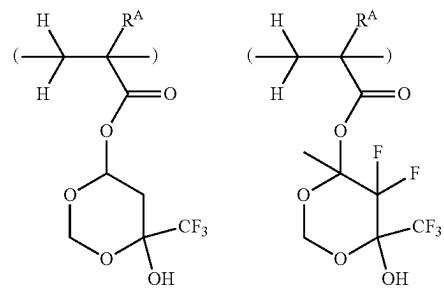




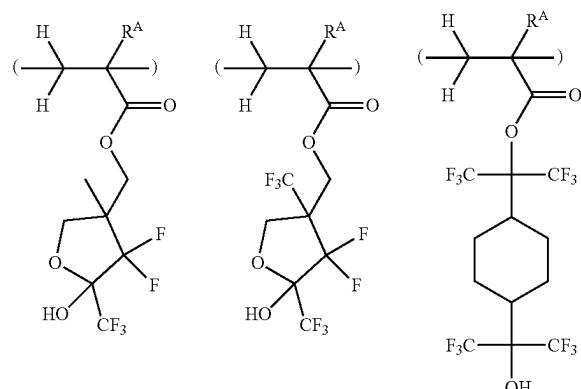
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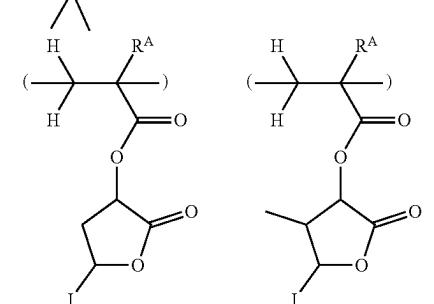
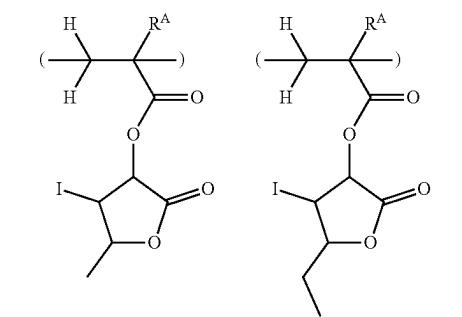
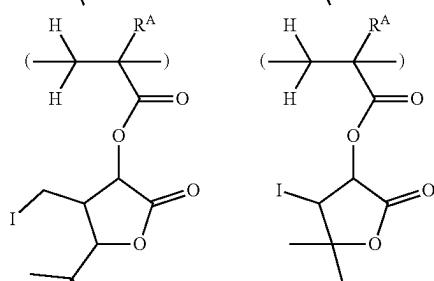
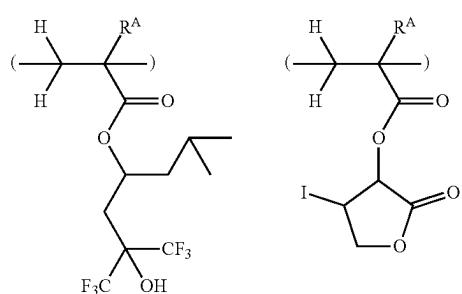
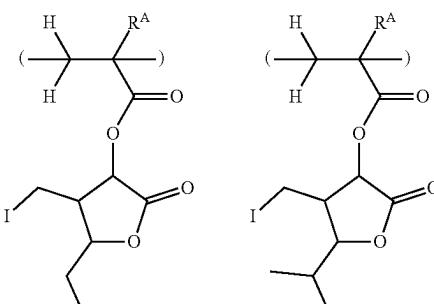
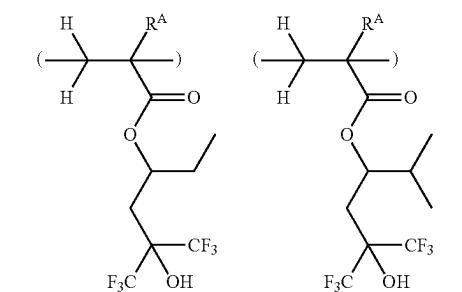
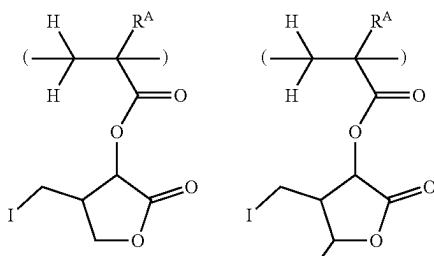
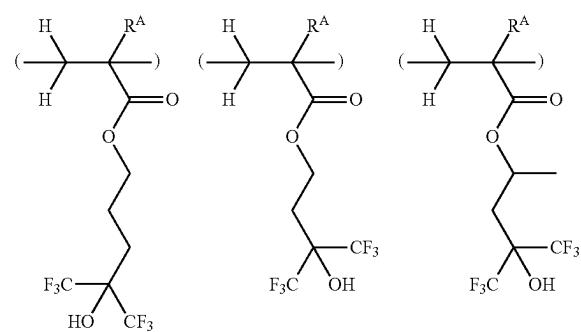
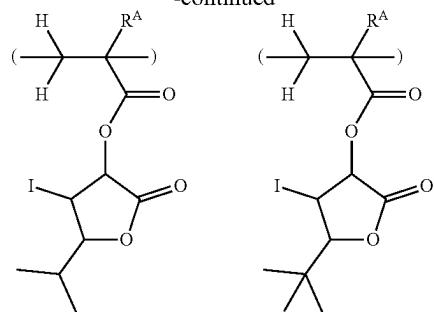
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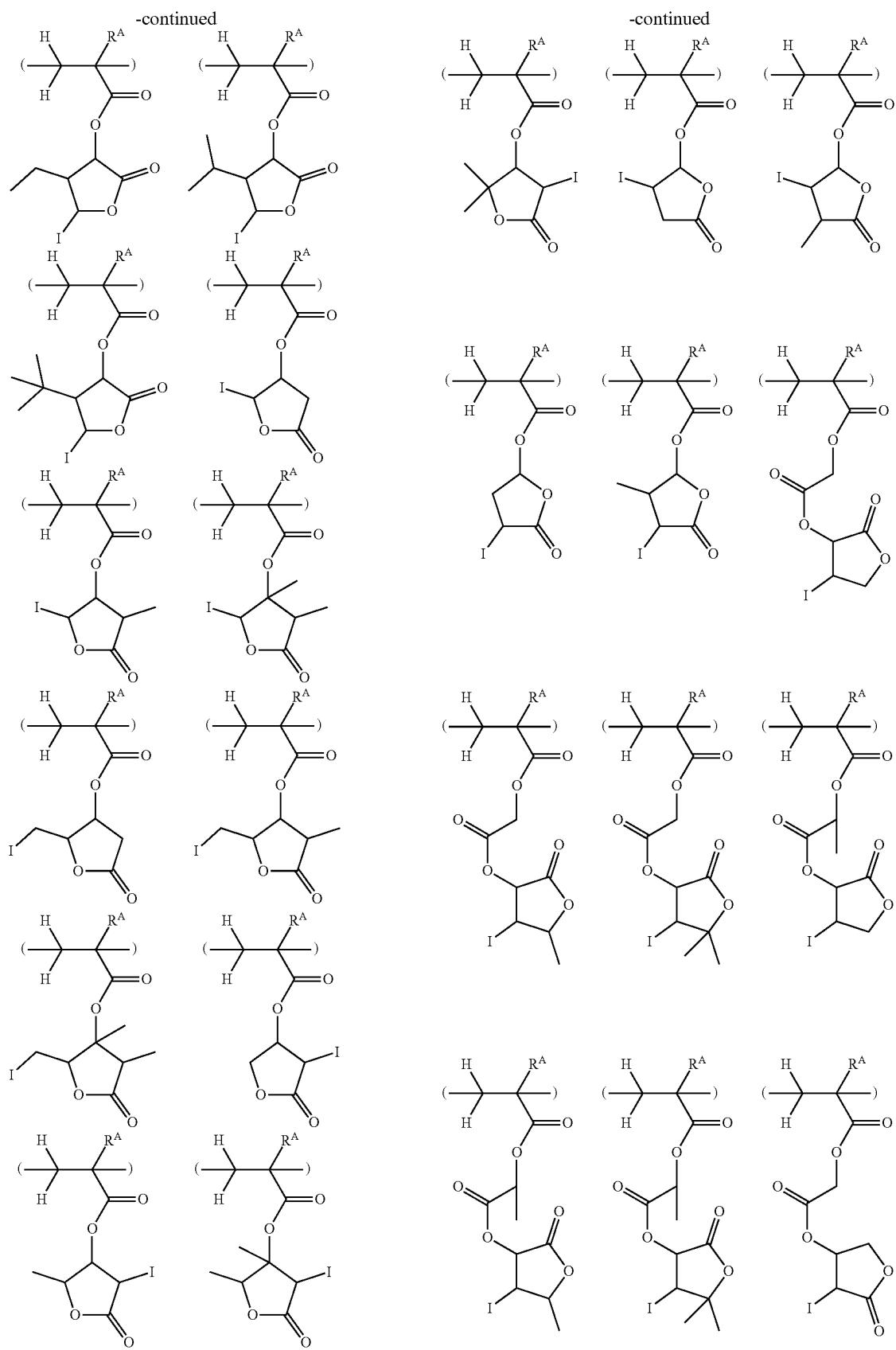


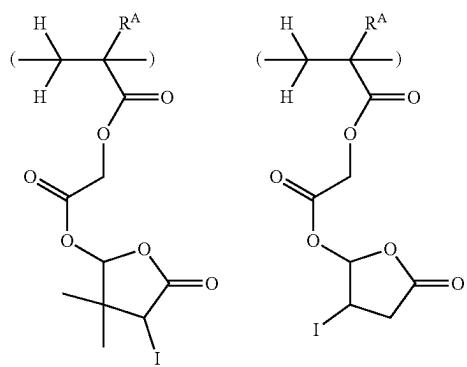
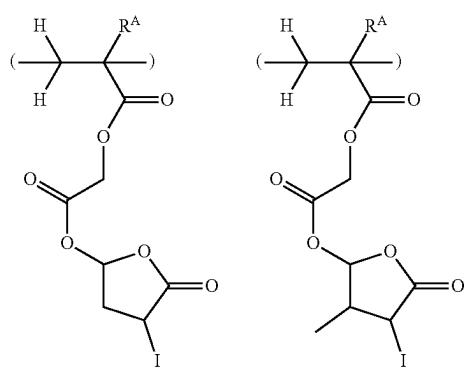
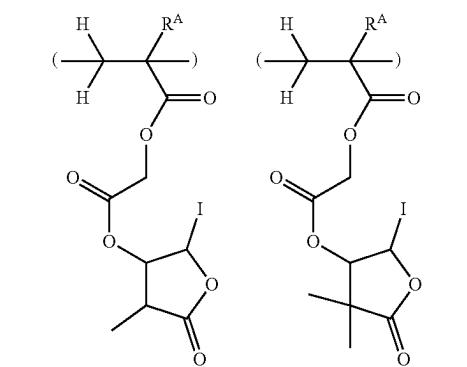
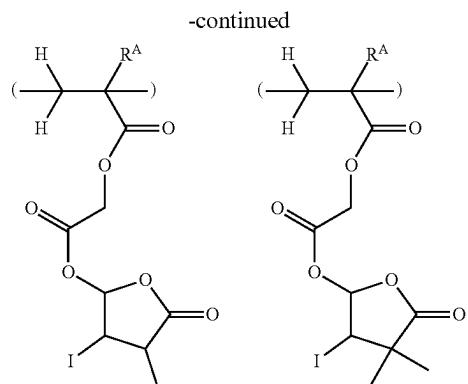
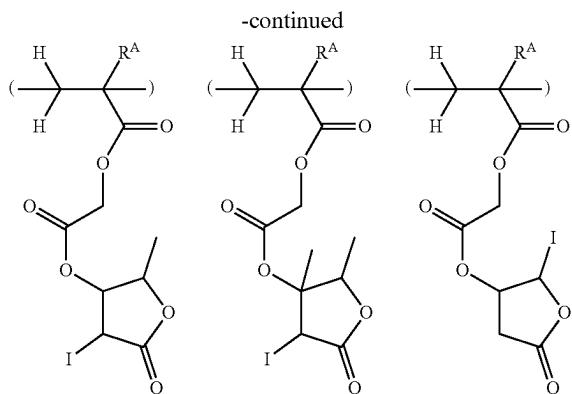
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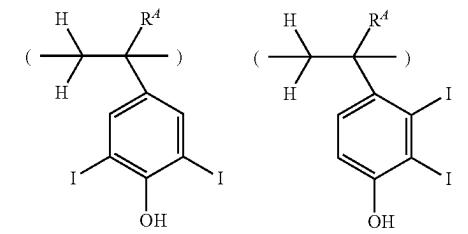
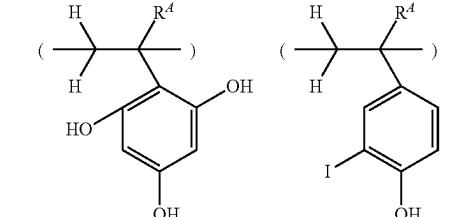
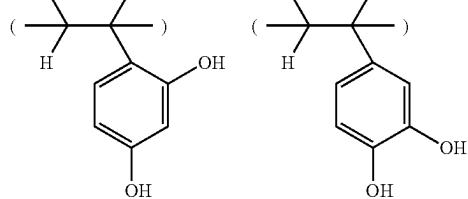
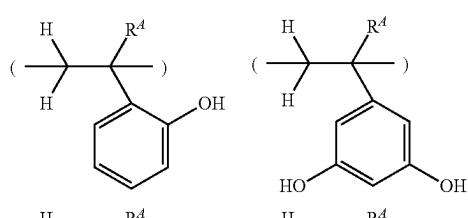
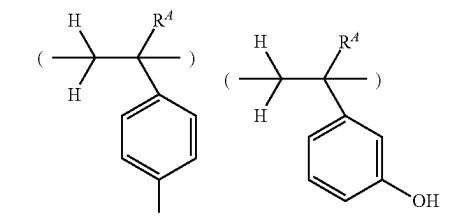
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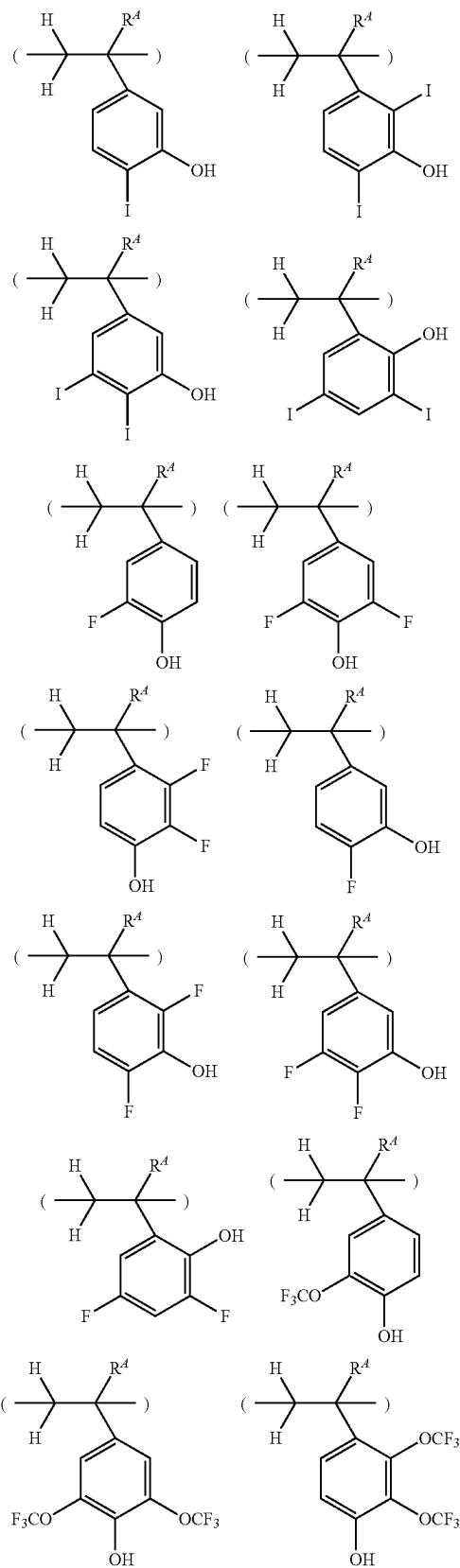




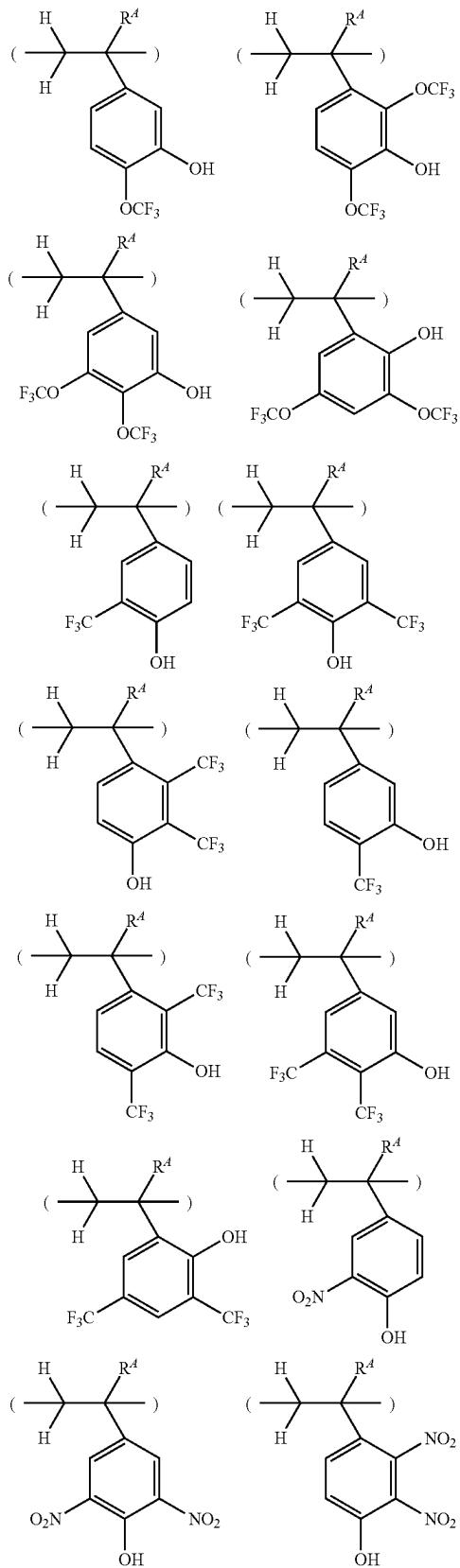
[0193] Examples of the repeat unit (b2) are shown below, but not limited thereto. Herein, R^A is as defined above.



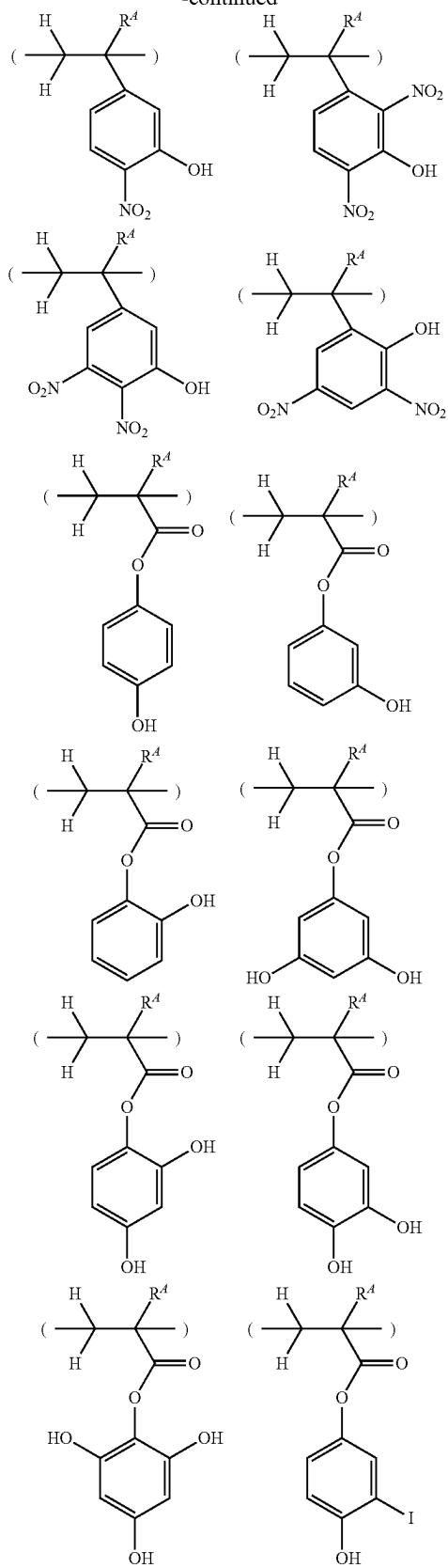
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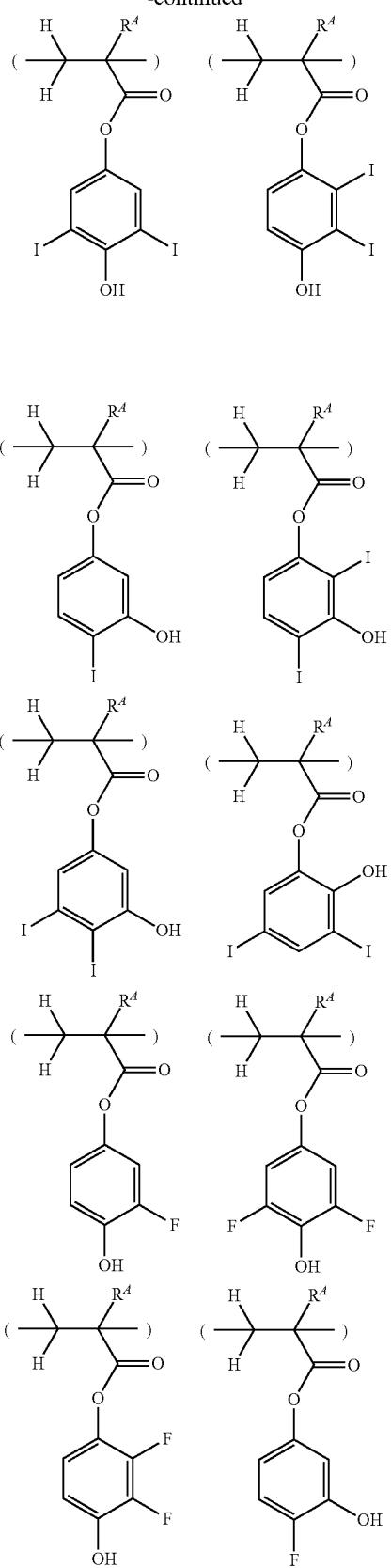
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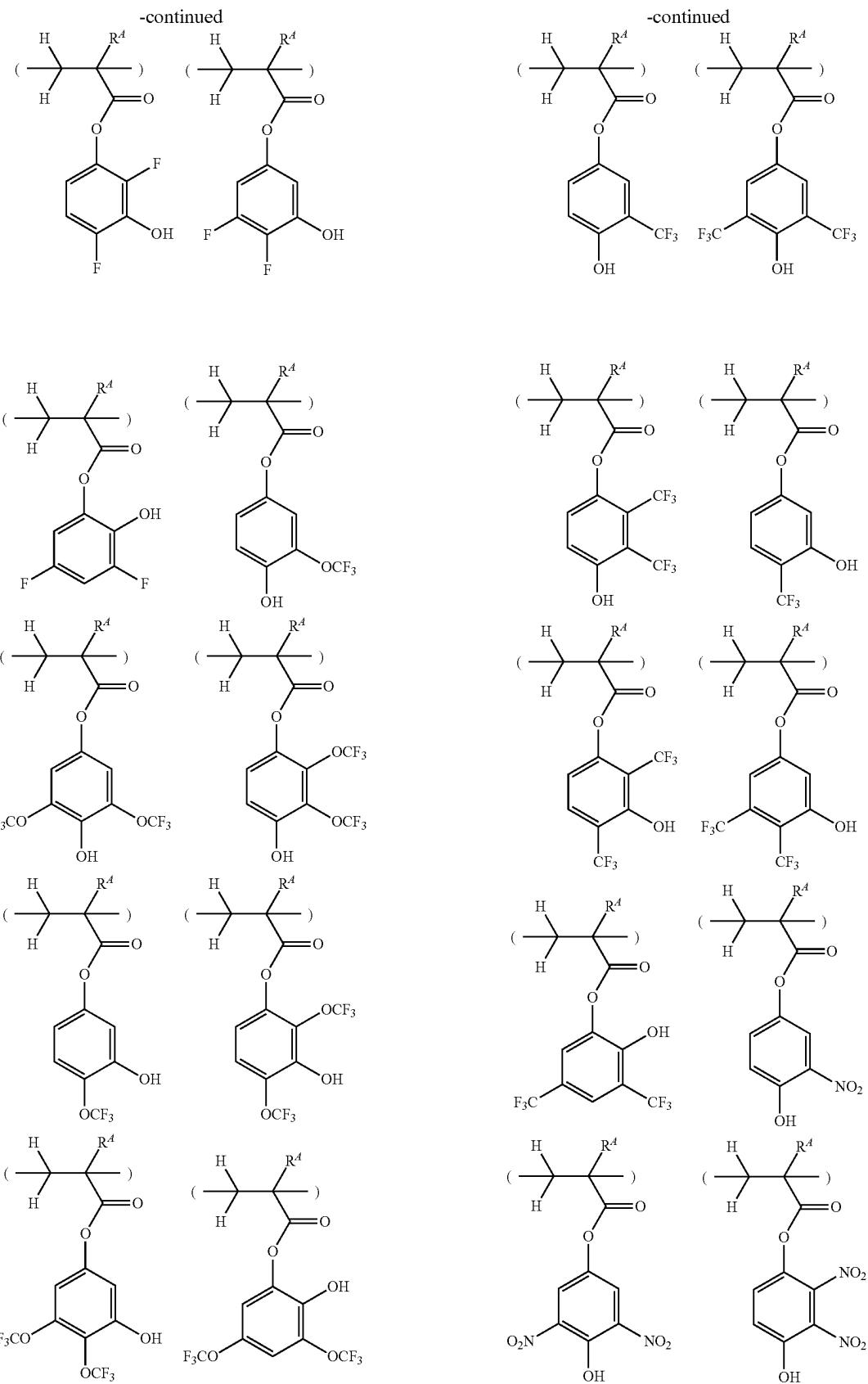


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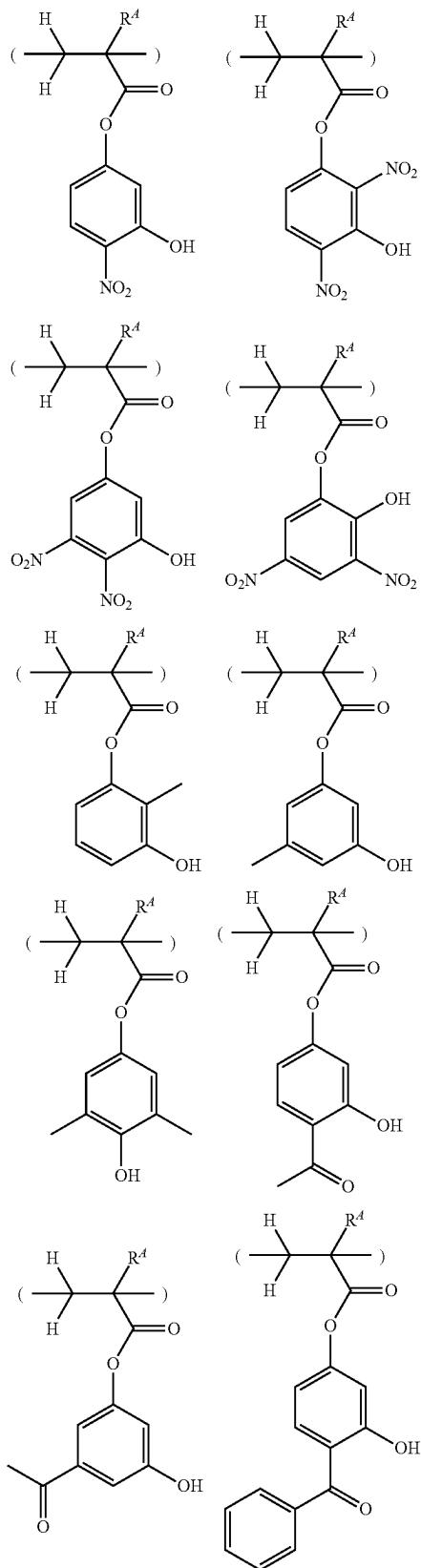


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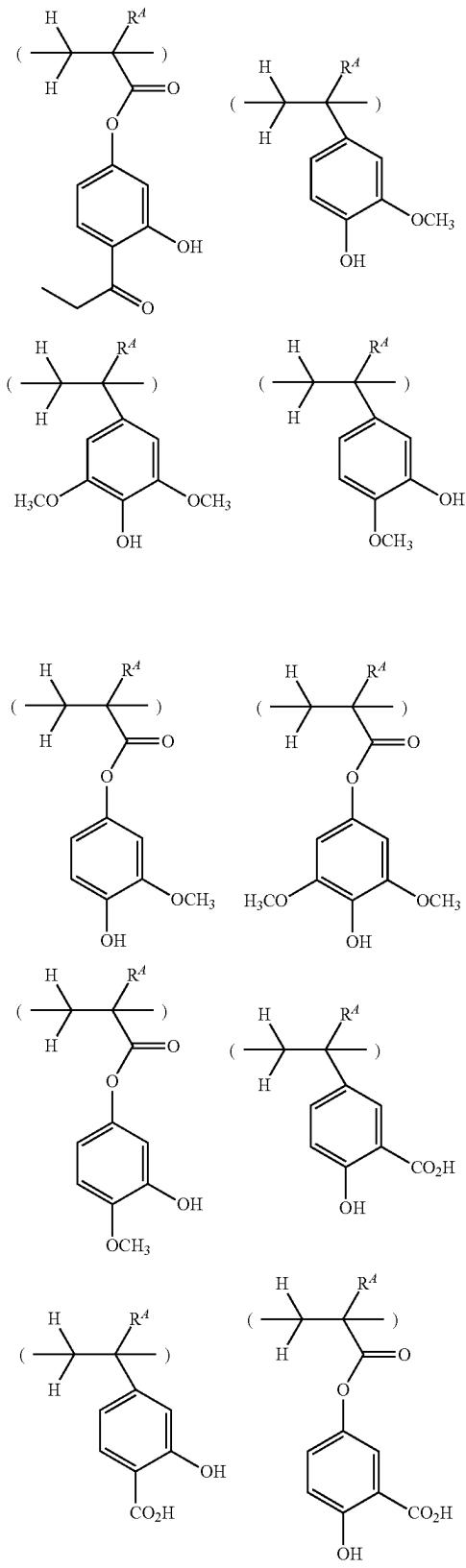


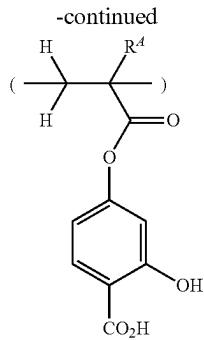


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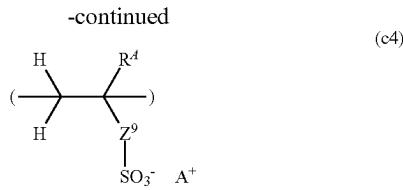
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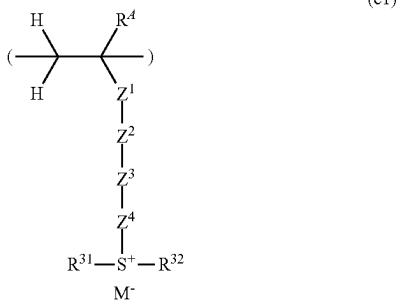
[0194] Of the repeat units (b1) and (b2), those units having a lactone ring as the polar group are preferred in the ArF lithography and those units having a phenolic site are preferred in the KrF, EB and EUV lithography.

[0195] The base polymer may further comprise repeat units of at least one type selected from repeat units having the formulae (c1) to (c4), which are simply referred to as repeat units (c1) to (c4).

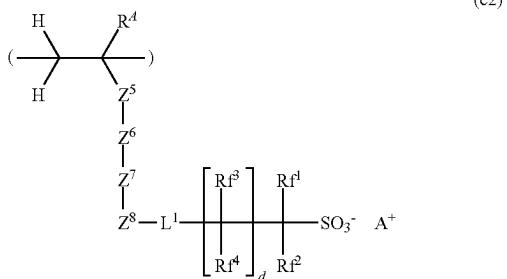


[0196] In formulae (c1) to (c4), R^A is each independently hydrogen, fluorine, methyl or trifluoromethyl. Z¹ is a single bond or optionally substituted phenylene group. Z² is a single bond, **—C(=O)—O—Z²¹—, **—C(=O)—N(H)—Z²¹— or **—O—Z²¹—. Z²¹ is a C₁-C₆ aliphatic hydrocarbylene group, a phenylene group or a divalent group obtained by combining the foregoing, which may contain halogen, carbonyl moiety, ester bond, ether bond or hydroxy moiety. Z³ is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond. Z⁴ is a single bond, or a C₁-C₆ aliphatic hydrocarbylene group, phenylene group or a divalent group obtained by combining the foregoing, which may contain halogen, carbonyl moiety, ester bond, ether bond or hydroxy moiety. Z⁵ is each independently a single bond, optionally substituted phenylene group, naphthylene group, or *—C(=O)—O—Z⁵¹. Z⁵¹ is a C₁-C₁₀ aliphatic hydrocarbylene group which may contain halogen, hydroxy moiety, ether bond, ester bond or lactone ring, or phenylene or naphthylene group. Z⁶ is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond. Z⁷ is each independently a single bond, ***—Z⁷¹—C(=O)—O—, ***—C(=O)—NH—Z⁷¹—, or ***—O—Z⁷¹—. Z⁷¹ is a C₁-C₂₀ hydrocarbylene group which may contain a heteroatom. Z⁸ is each independently a single bond, ***—Z⁸¹—C(=O)—O—, ***—C(=O)—NH—Z⁸¹—, or ***—O—Z⁸¹—. Z⁸¹ is a C₁-C₂₀ hydrocarbylene group which may contain a heteroatom. Z⁹ is a single bond, methylene, ethylene, phenylene, fluorinated phenylene, trifluoromethyl-substituted phenylene, *—C(=O)—O—Z⁹¹—, *—C(=O)—N(H)—Z⁹¹—, or *—O—Z⁹¹—. Z⁹¹ is a C₁-C₆ aliphatic hydrocarbylene group, phenylene group, fluorinated phenylene group or trifluoromethyl-substituted phenylene group, which may contain a carbonyl moiety, ester bond, ether bond or hydroxy moiety. The asterisk * designates a point of attachment to the carbon atom in the backbone, ** designates a point of attachment to Z¹, *** designates a point of attachment to Z⁶, and **** designates a point of attachment to Z⁷.

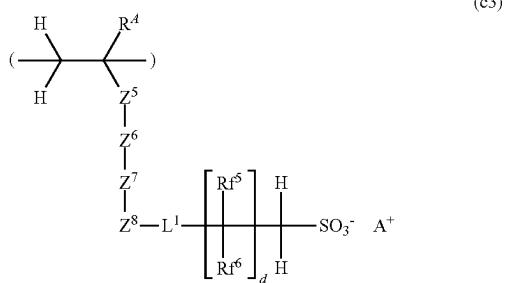
(c1)



(c2)

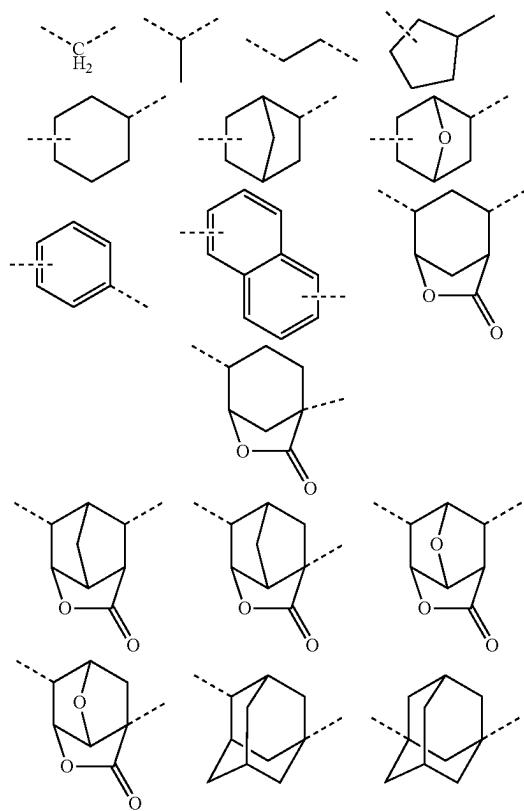


(c3)



[0197] The aliphatic hydrocarbylene group represented by Z²¹, Z⁵¹ and Z⁹¹ may be straight, branched or cyclic. Examples thereof include alkanediyl groups such as methanediyl, ethane-1,1-diyl, ethane-1,2-diyl, propane-1,1-diyl, propane-1,2-diyl, propane-1,3-diyl, propane-2,2-diyl, butane-1,1-diyl, butane-1,2-diyl, butane-1,3-diyl, butane-2,3-diyl, butane-1,4-diyl, 1,1-dimethylethane-1,2-diyl, pentane-1,5-diyl, 2-methylbutane-1,2-diyl, and hexane-1,6-diyl; cycloalkanediyl groups such as cyclopropanediyl, cyclobutanediyl, cyclopentanediyl and cyclohexanediyl, and combinations thereof.

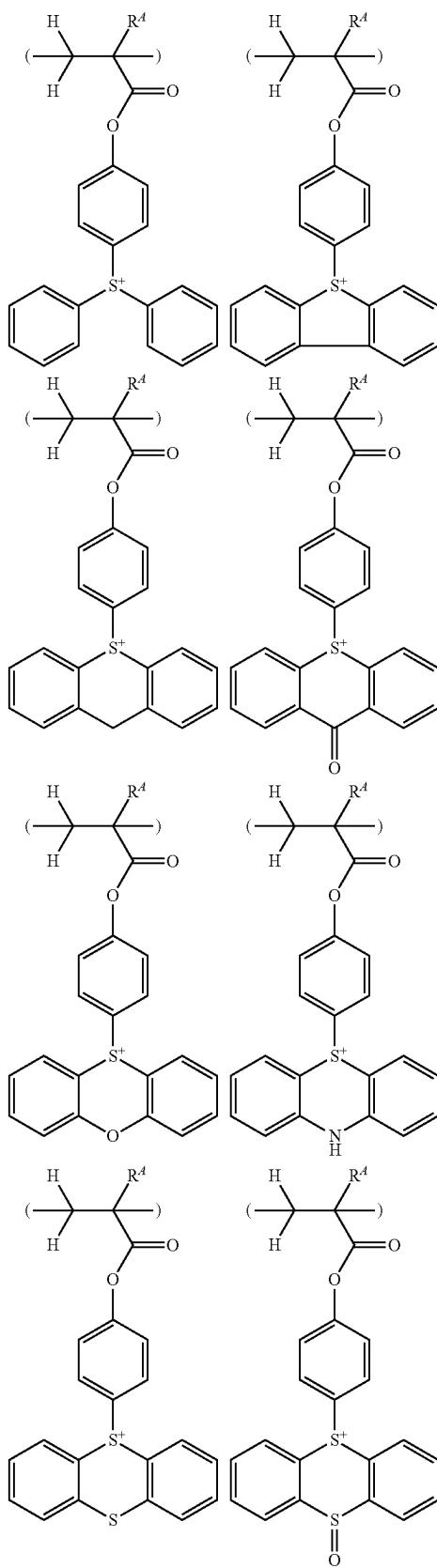
[0198] The hydrocarbylene group which may contain a heteroatom, represented by Z⁷¹ and Z⁸¹, may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are shown below, but not limited thereto.



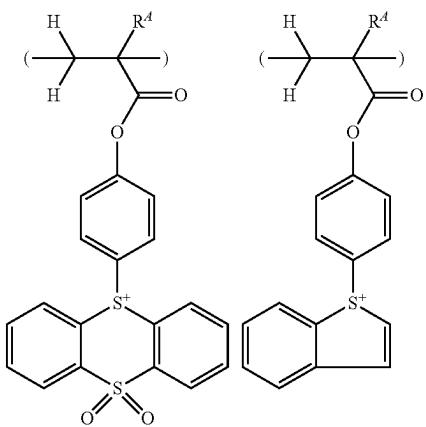
[0199] In formula (c1), R^{31} and R^{32} are each independently a C_1 - C_{20} hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C_1 - C_{20} alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, and tert-butyl; C_3 - C_{20} cyclic saturated hydrocarbyl groups such as cyclopropyl, cyclopentyl, cyclohexyl, cyclopropylmethyl, 4-methylcyclohexyl, cyclohexylmethyl, norbornyl, and adamantyl; C_2 - C_{20} alkenyl groups such as vinyl, allyl, propenyl, butenyl, and hexenyl; C_3 - C_{20} cyclic unsaturated hydrocarbyl groups such as cyclohexenyl; C_6 - C_{20} aryl groups such as phenyl, naphthyl and thiienyl; C_7 - C_{20} aralkyl groups such as benzyl, 1-phenylethyl, and 2-phenylethyl, and combinations thereof. Of these, aryl groups are preferred. In the hydrocarbyl group, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some $—CH_2—$ may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride ($—C(=O)—O—C(=O)O—$) or haloalkyl moiety.

[0200] R^{31} and R^{32} may bond together to form a ring with the sulfur atom to which they are attached. Examples of the ring are as will be exemplified later for the ring that R^{c1} and R^{c2} in formula (cation-1) form with the sulfur atom to which they are attached.

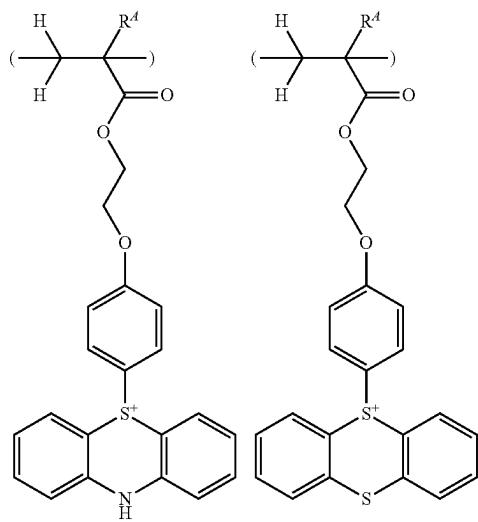
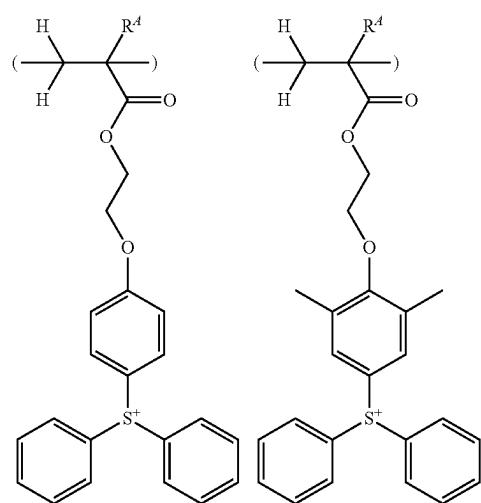
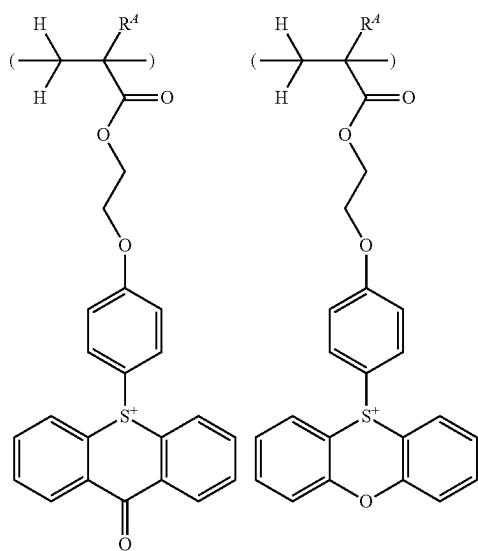
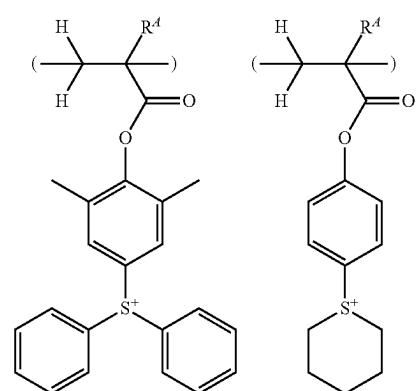
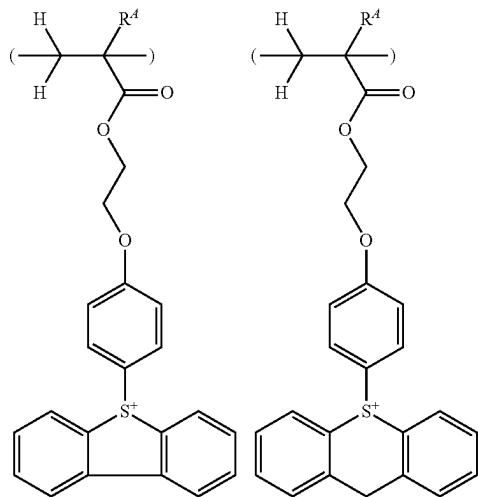
[0201] Examples of the cation in repeat unit (c1) are given below, but not limited thereto. Herein R^A is as defined above.



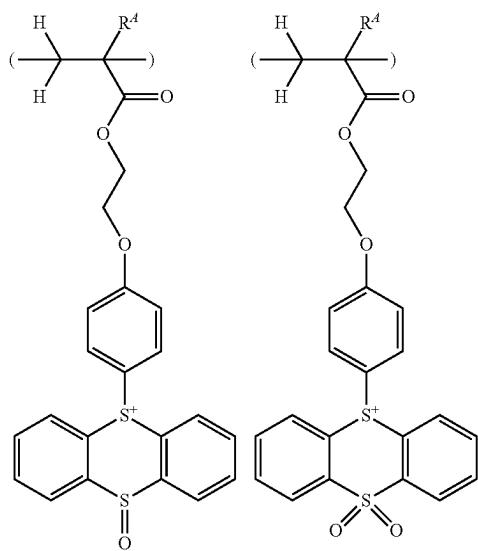
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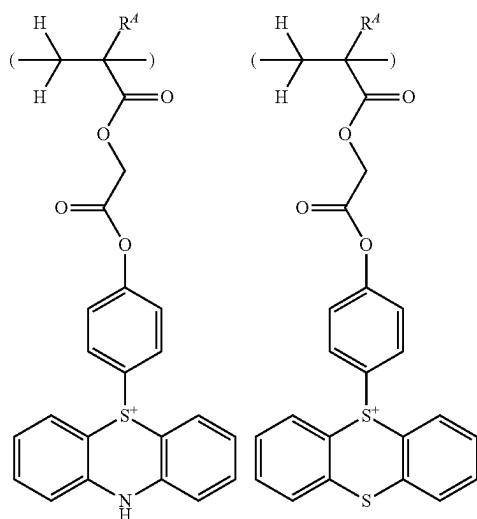
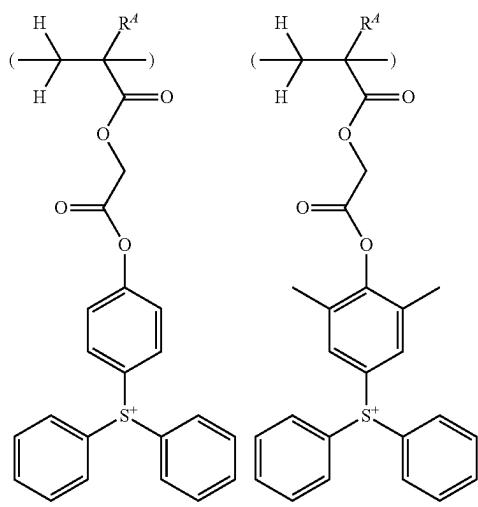
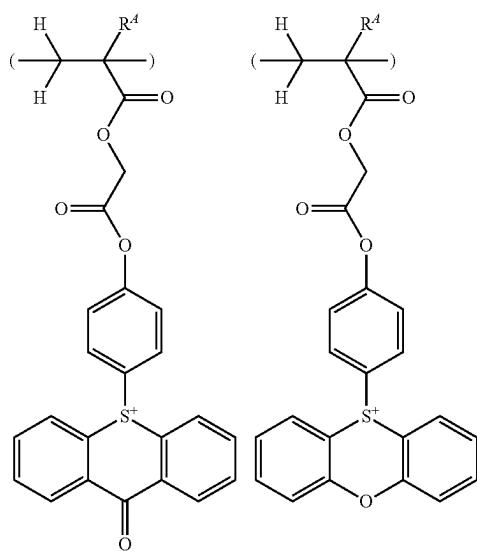
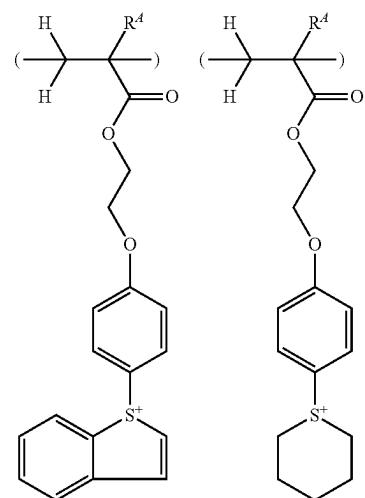
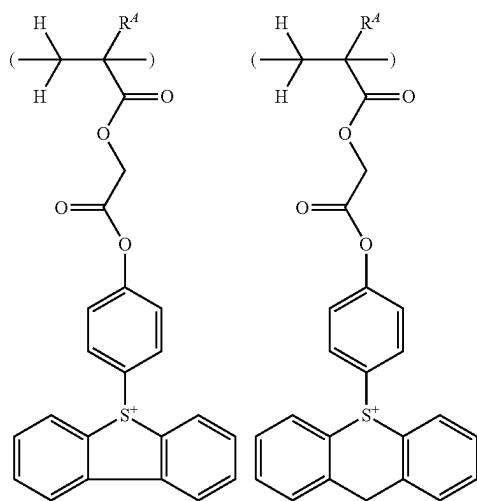
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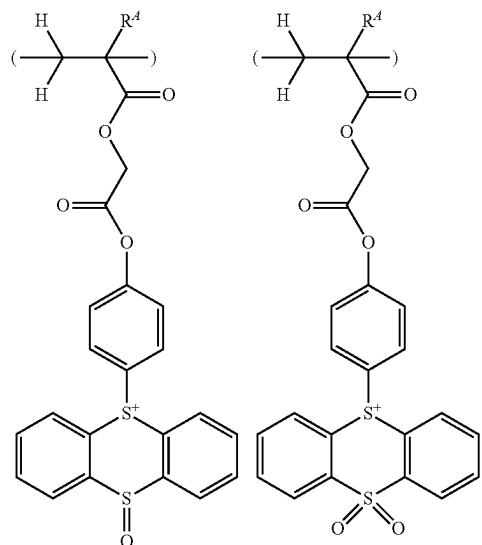
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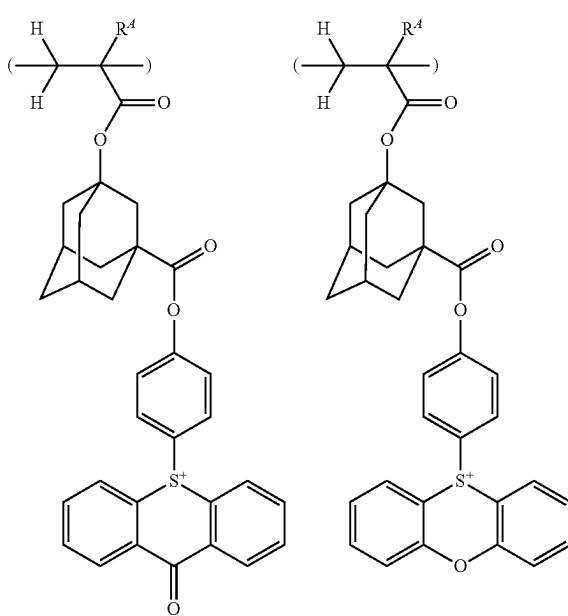
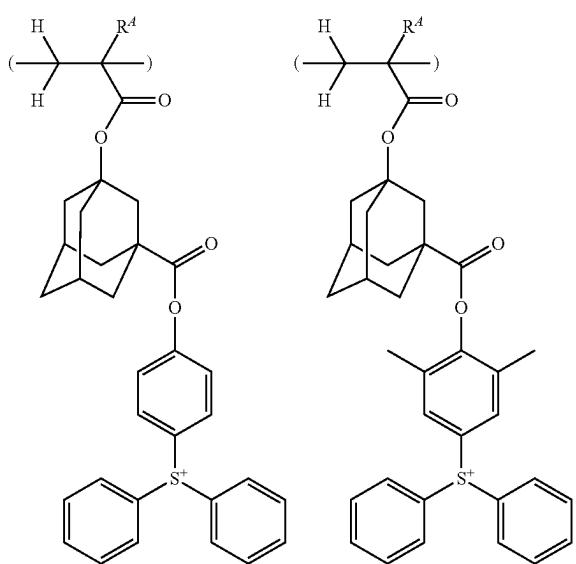
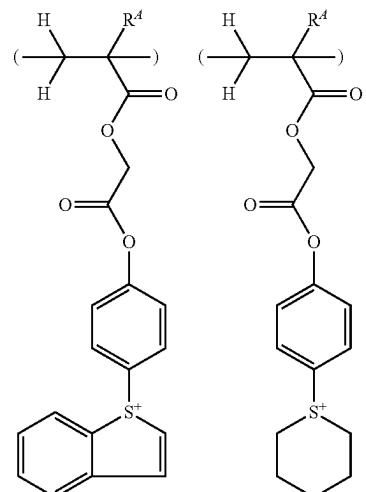
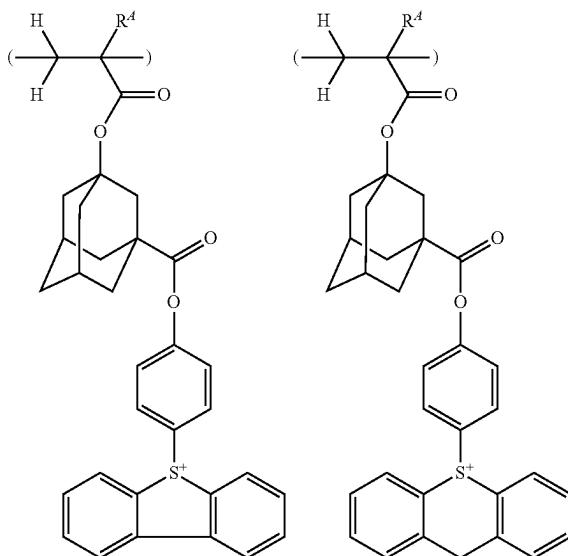
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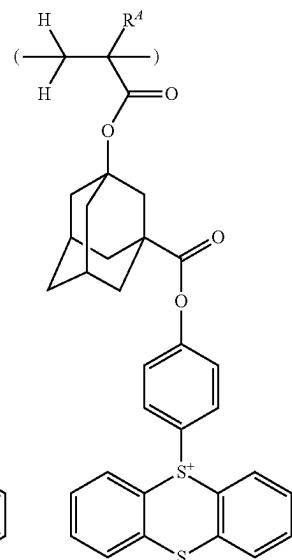
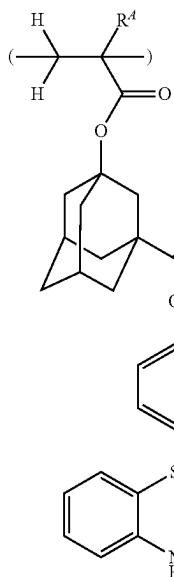
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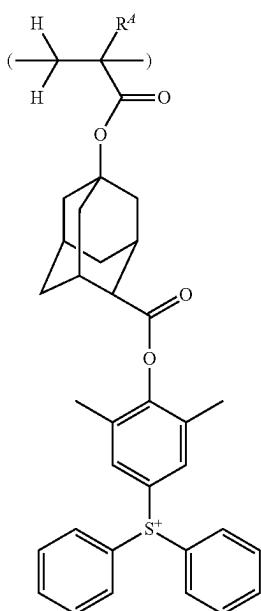
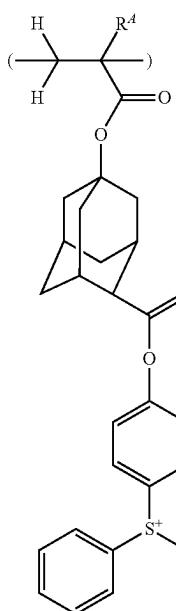
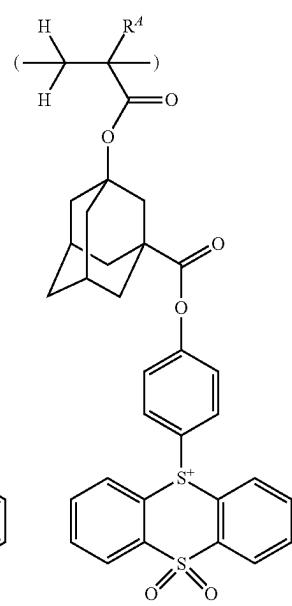
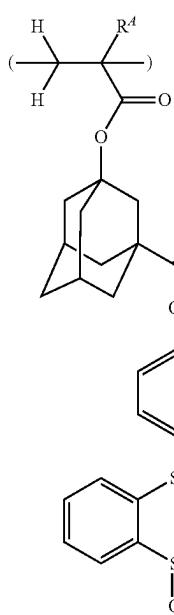
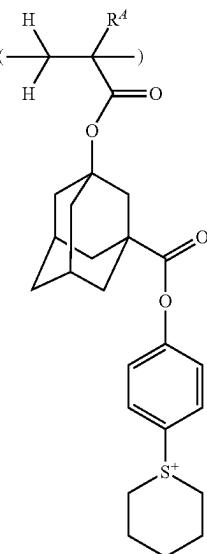
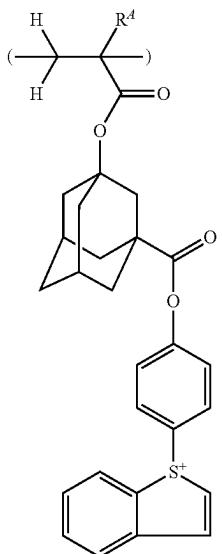
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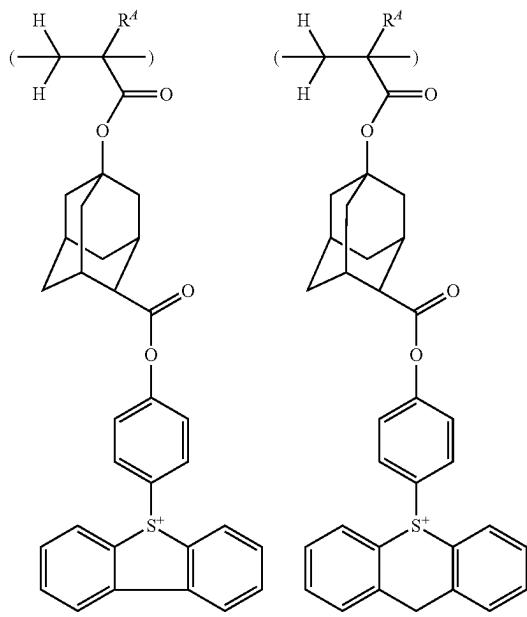
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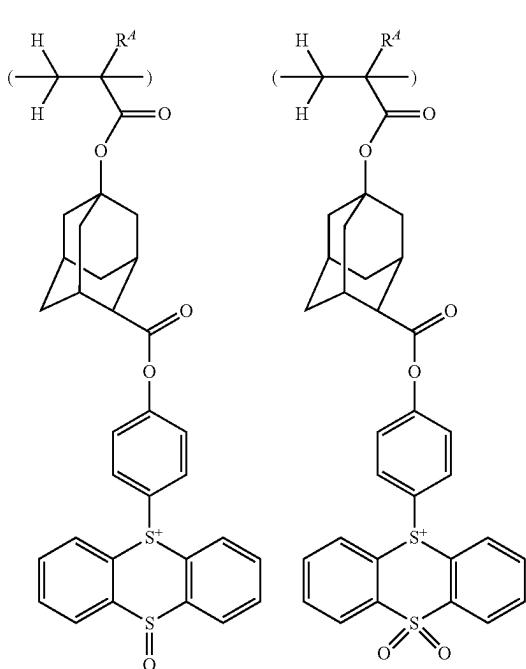
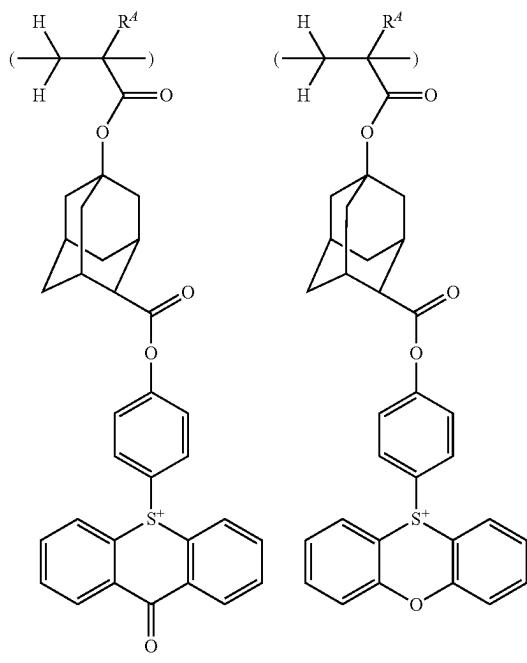
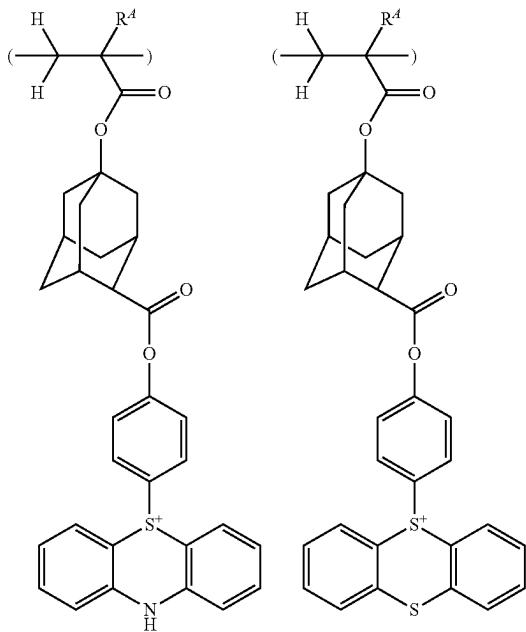
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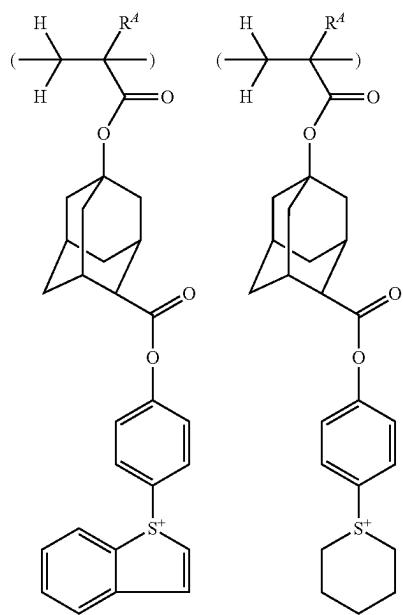
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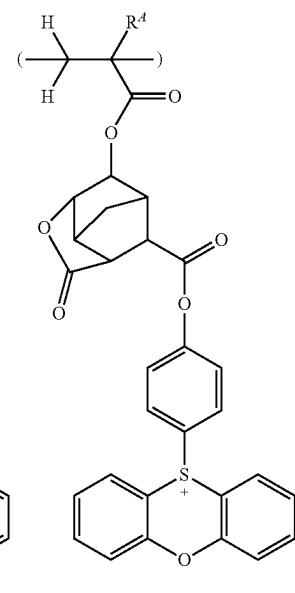
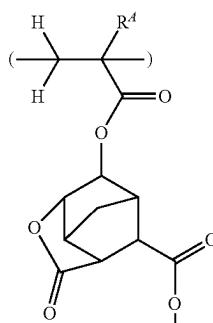
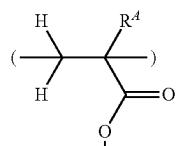
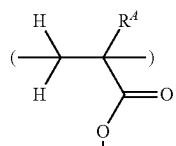
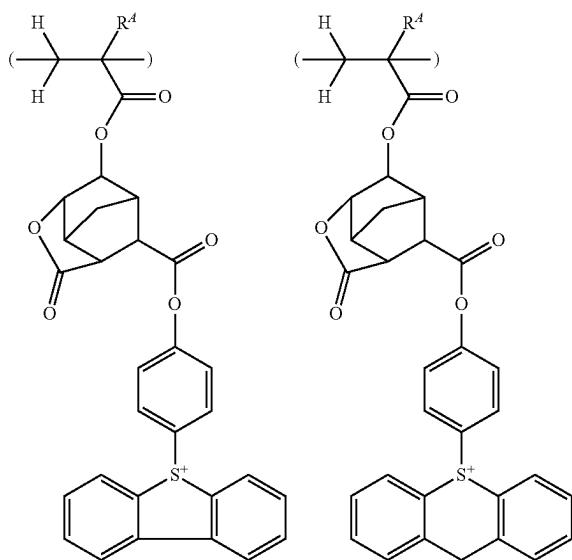
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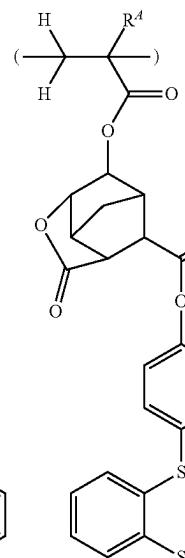
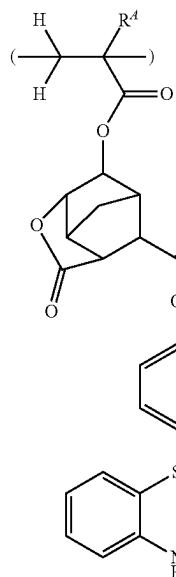


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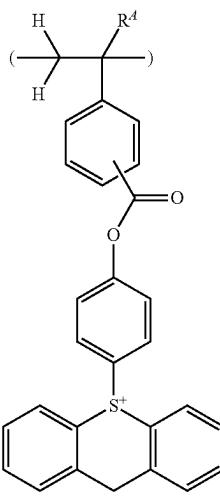
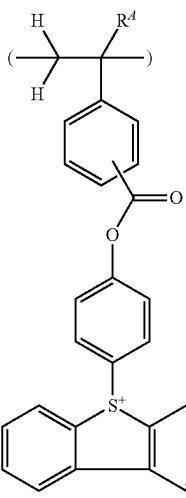
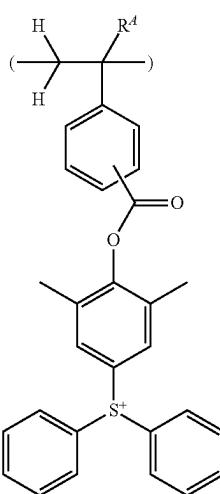
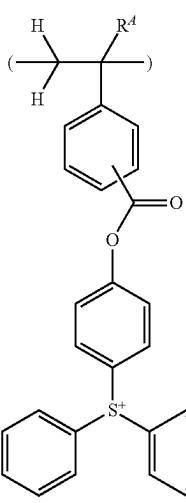
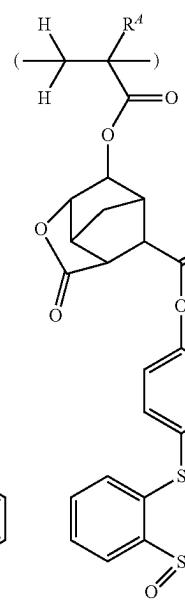
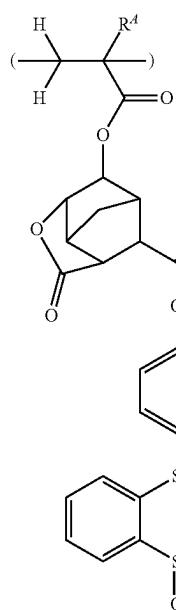
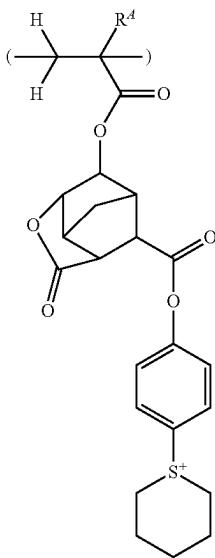
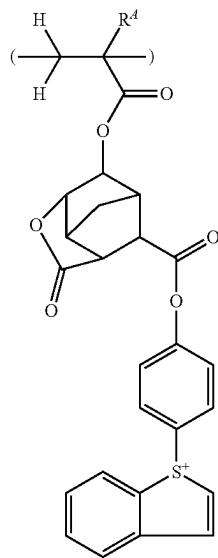


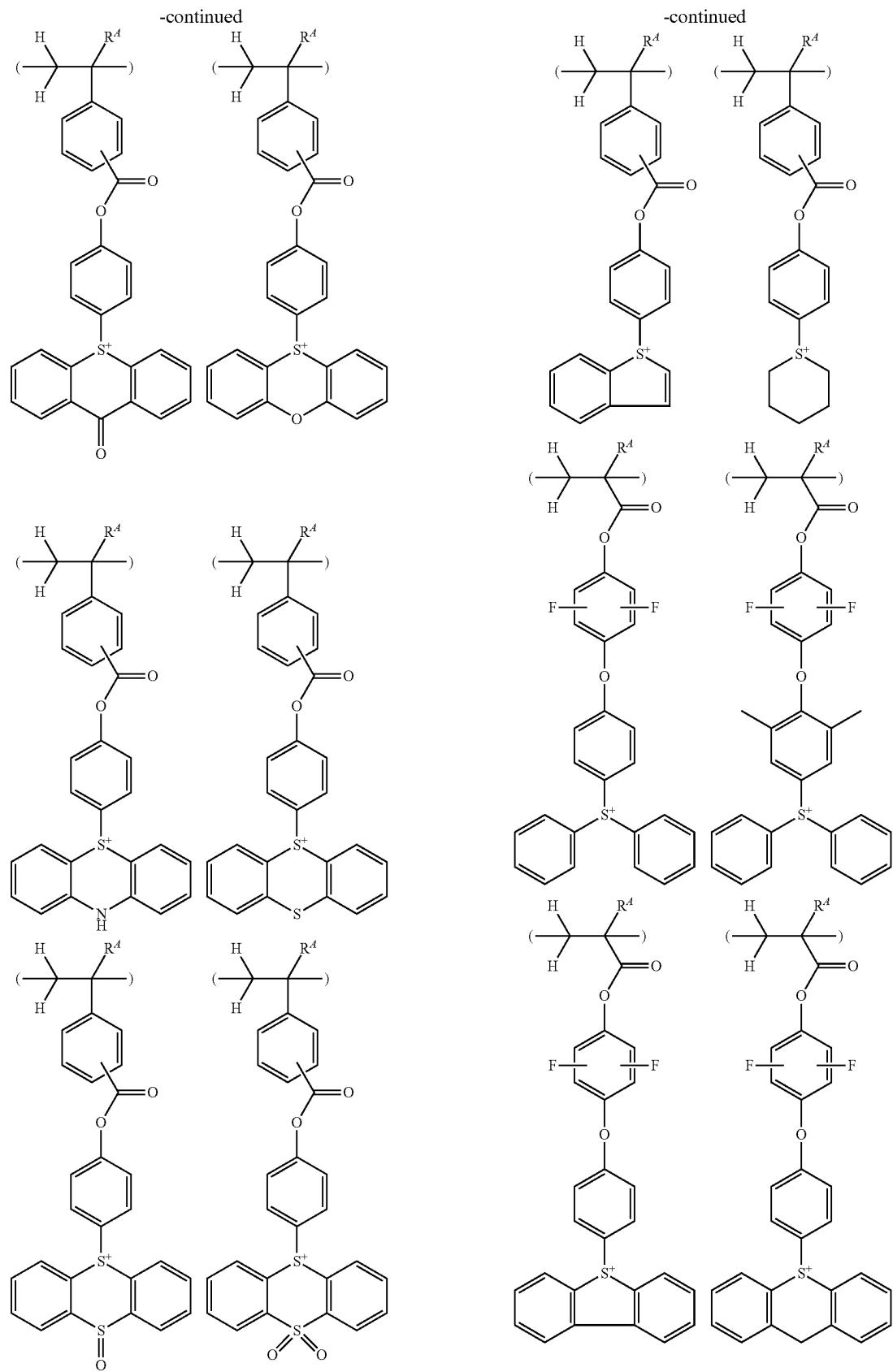
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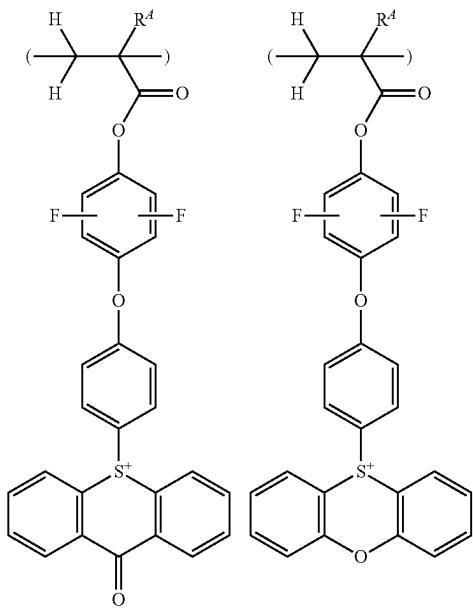


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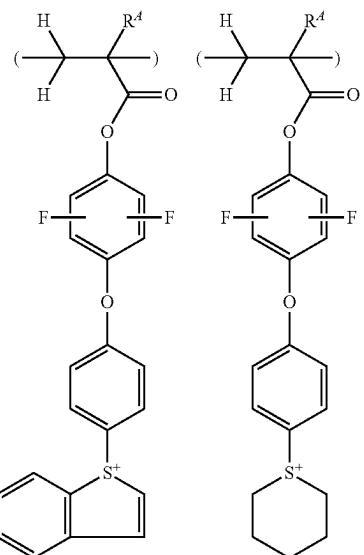
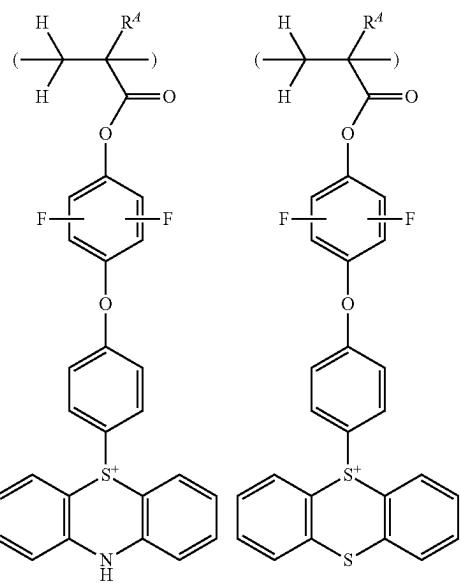
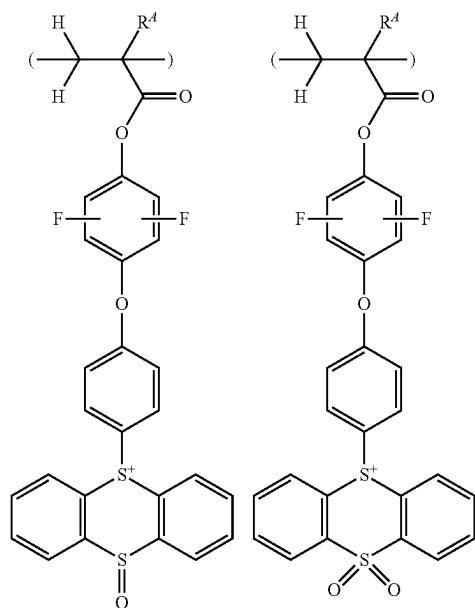




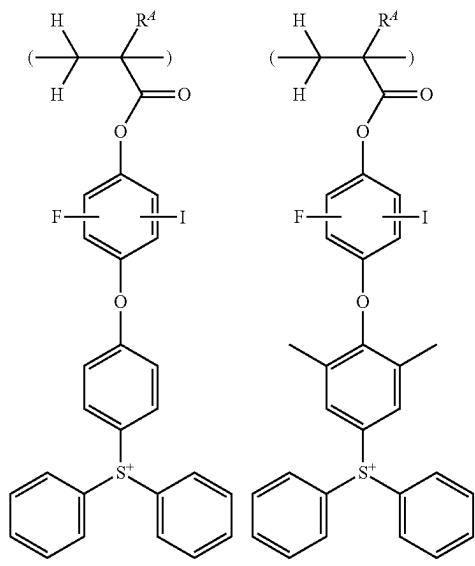
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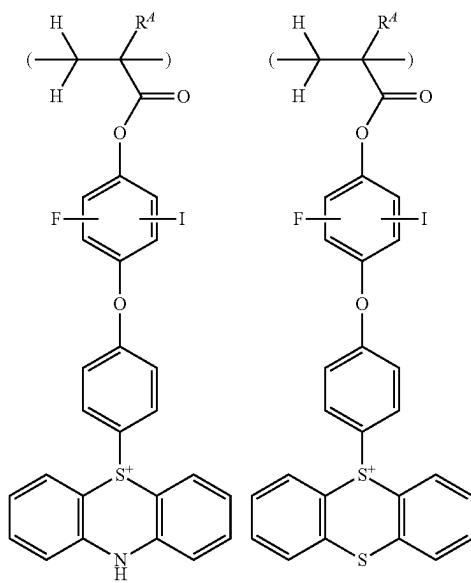
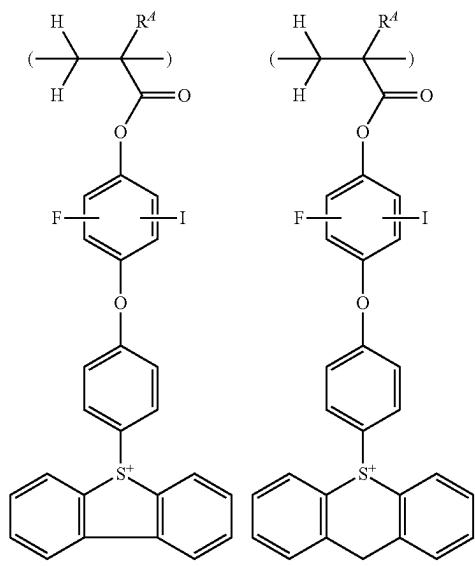
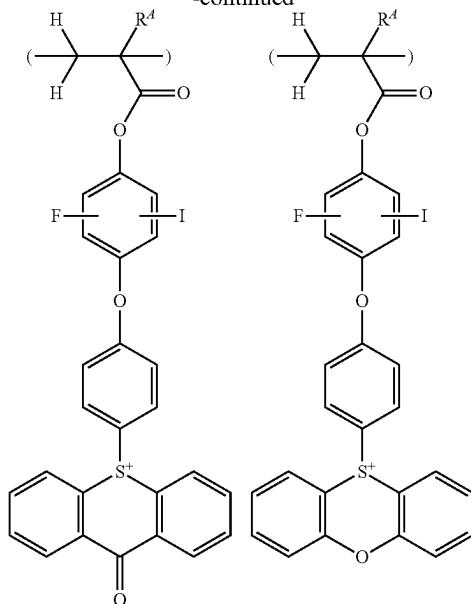
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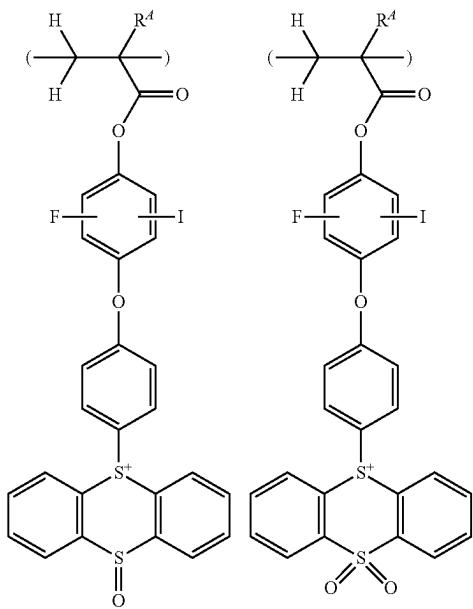
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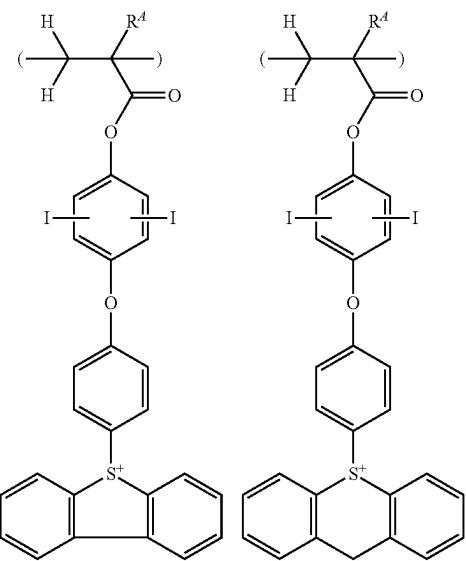
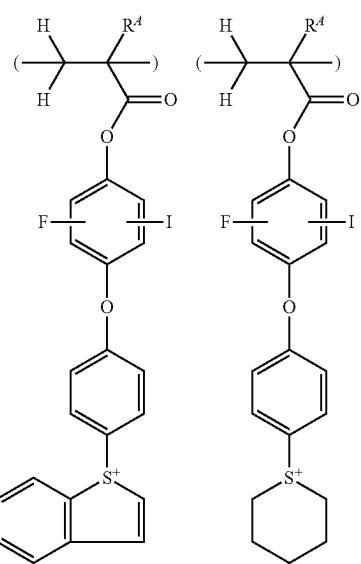
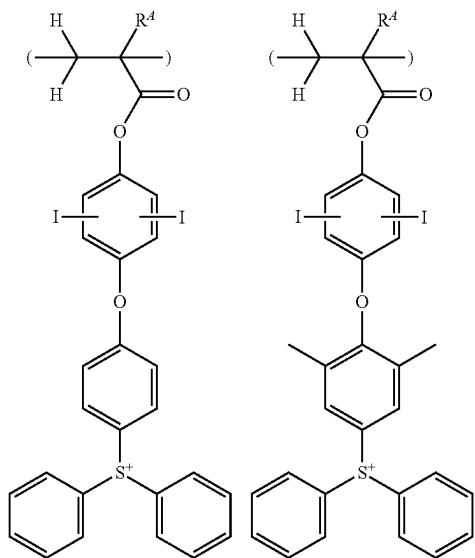
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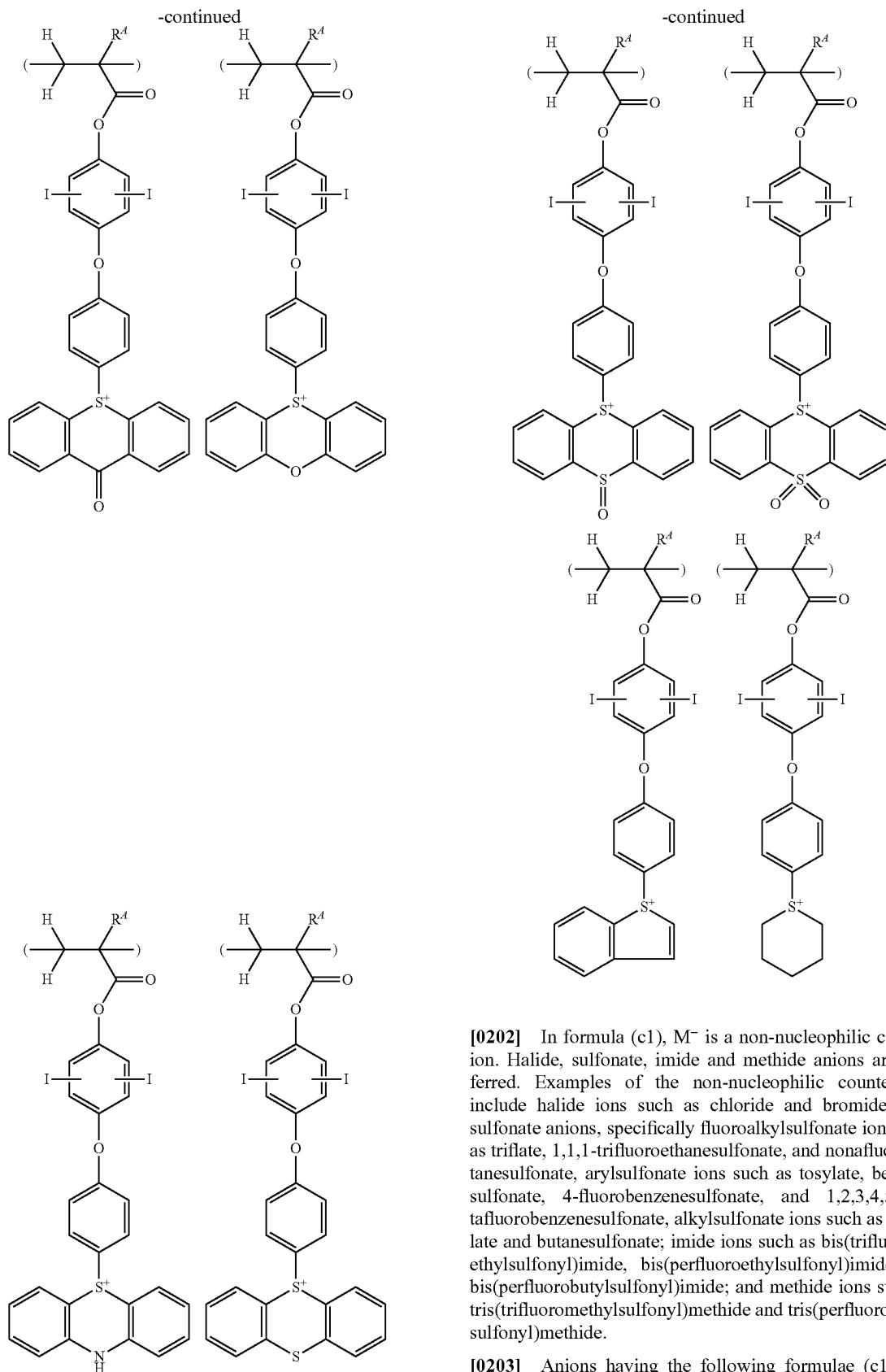


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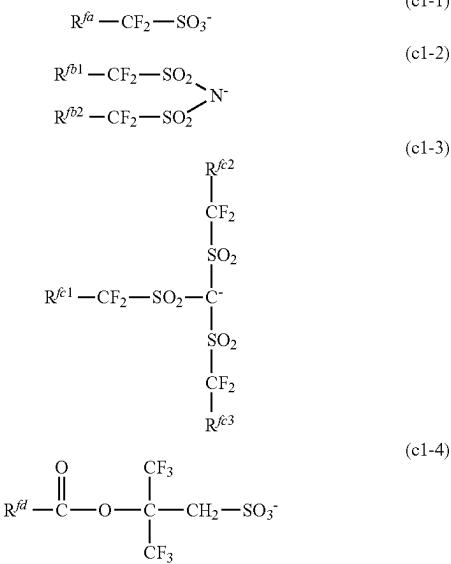
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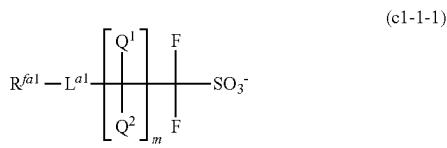
[0202] In formula (c1), M^- is a non-nucleophilic counter ion. Halide, sulfonate, imide and methide anions are preferred. Examples of the non-nucleophilic counter ion include halide ions such as chloride and bromide ions; sulfonate anions, specifically fluoroalkylsulfonate ions such as triflate, 1,1,1-trifluoroethanesulfonate, and nonafluorobutanesulfonate, arylsulfonate ions such as tosylate, benzene sulfonate, 4-fluorobenzenesulfonate, and 1,2,3,4,5-pentafluorobenzenesulfonate, alkylsulfonate ions such as mesylate and butanesulfonate; imide ions such as bis(trifluoromethylsulfonyl)imide, bis(perfluoroethylsulfonyl)imide and bis(perfluorobutylsulfonyl)imide; and methide ions such as tris(trifluoromethylsulfonyl)methide and tris(perfluoroethylsulfonyl)methide.

[0203] Anions having the following formulae (c1-1) to (c1-4) are also useful as the non-nucleophilic counter ion.



[0204] In formula (c1-1), R^{fa} is fluorine or a $\text{C}_1\text{-}\text{C}_{40}$ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as will be exemplified below for the hydrocarbyl group R^{fa} in formula (c1-1-1).

[0205] Of the anions of formula (c1-1), an anion having the formula (c1-1-1) is preferred.



[0206] In formula (c1-1-1), Q^1 and Q^2 are each independently hydrogen, fluorine or a $\text{C}_1\text{-}\text{C}_6$ fluorinated saturated hydrocarbyl group. It is preferred for solvent solubility that at least one of Q^1 and Q^2 be trifluoromethyl. The subscript m is an integer of 0 to 4, most preferably 1.

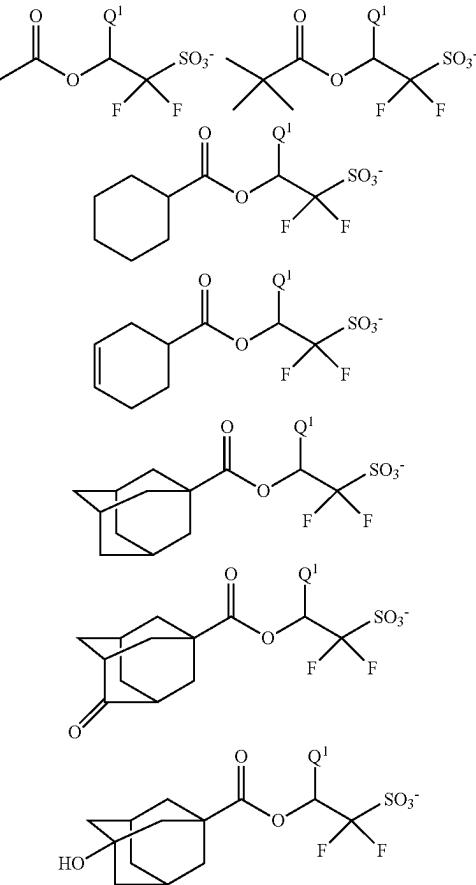
[0207] R^{fa1} is a $\text{C}_1\text{-}\text{C}_{35}$ hydrocarbyl group which may contain a heteroatom. As the heteroatom, oxygen, nitrogen, sulfur and halogen atoms are preferred, with oxygen being most preferred. Of the hydrocarbyl groups, those groups of 6 to 30 carbon atoms are preferred from the aspect of achieving a high resolution in forming patterns of small feature size. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include $\text{C}_1\text{-}\text{C}_{35}$ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, pentyl, neopentyl, hexyl, heptyl, 2-ethylhexyl, nonyl, undecyl, tridecyl, pentadecyl, heptadecyl, and icosyl; $\text{C}_3\text{-}\text{C}_{35}$ cyclic saturated hydrocarbyl groups such as cyclopentyl, cyclohexyl, 1-adamantyl, 2-adamantyl, 1-adamantylmethyl, norbornyl, norbornylmethyl, tricyclodecyl, tetracyclododecyl, tetracyclododecylmethyl, and dicyclohexylmethyl; $\text{C}_2\text{-}\text{C}_{35}$ unsaturated aliphatic hydrocarbyl groups such as allyl and 3-cyclohexenyl; $\text{C}_6\text{-}\text{C}_{35}$ aryl

groups such as phenyl, 1-naphthyl, 2-naphthyl and 9-fluorenyl; and $\text{C}_7\text{-}\text{C}_{35}$ aralkyl groups such as benzyl and diphenylmethyl, and combinations thereof.

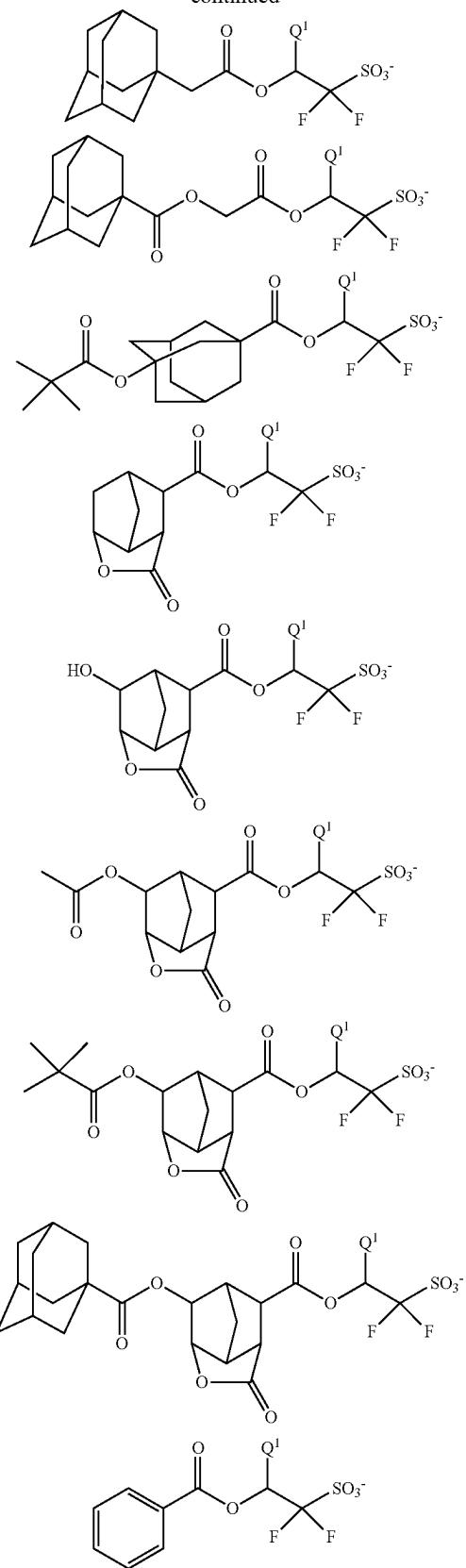
[0208] In the foregoing hydrocarbyl groups, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, or some constituent $-\text{CH}_2-$ may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, fluorine, chlorine, bromine, iodine, cyano, nitro, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride ($-\text{C}(=\text{O})-\text{O}-\text{C}(=\text{O})-$) or haloalkyl moiety. Examples of the heteroatom-containing hydrocarbyl group include tetrahydrofuryl, methoxymethyl, ethoxymethyl, methylthiomethyl, acetamidomethyl, trifluoroethyl, (2-methoxyethoxy)methyl, acetoxyethyl, 2-carboxy-1-cyclohexyl, 2-oxopropyl, 4-oxo-1-adamantyl, and 3-oxocyclohexyl.

[0209] In formula (c1-1-1), L^{a1} is a single bond, ether bond, ester bond, sulfonate ester bond, carbonate bond or carbamate bond. From the aspect of synthesis, an ether bond or ester bond is preferred, with the ester bond being more preferred.

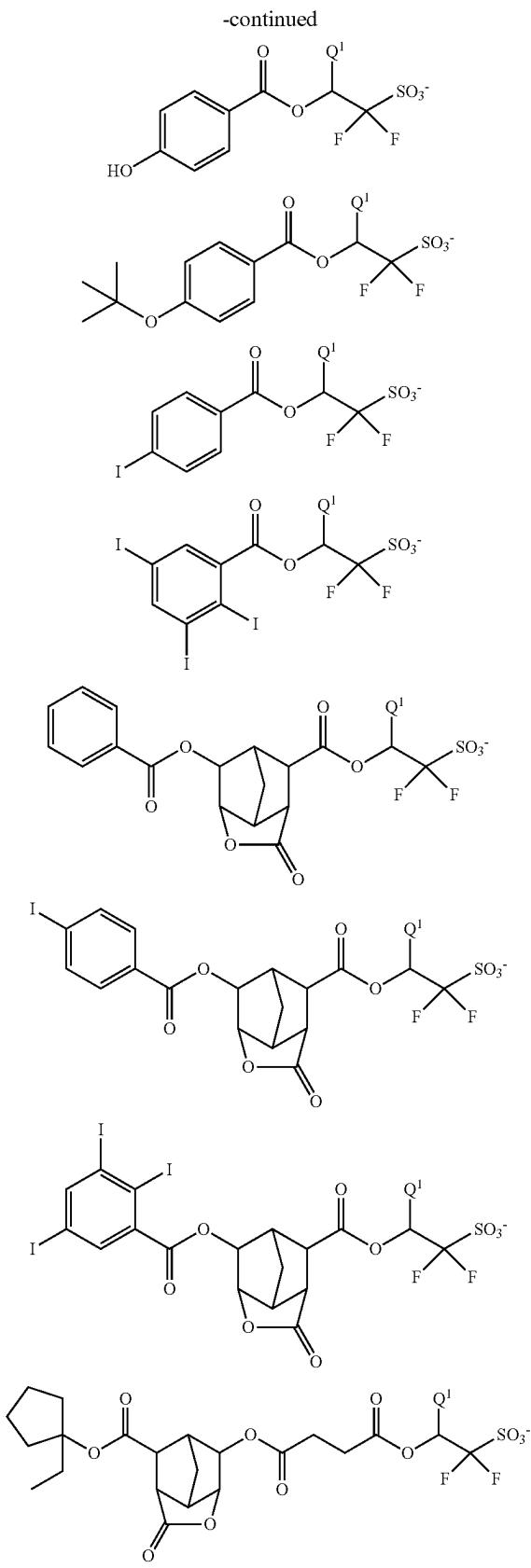
[0210] Examples of the anion having formula (c1-1) are shown below, but not limited thereto. Herein Q^1 is as defined above.



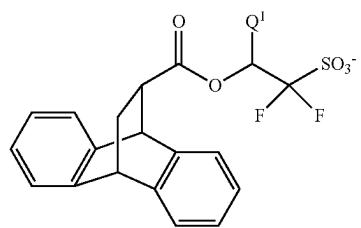
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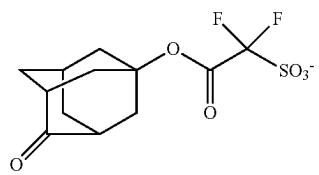
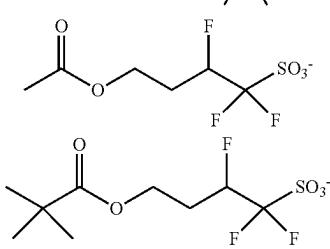
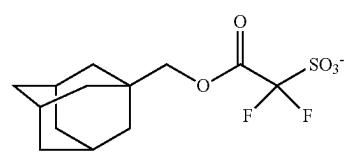
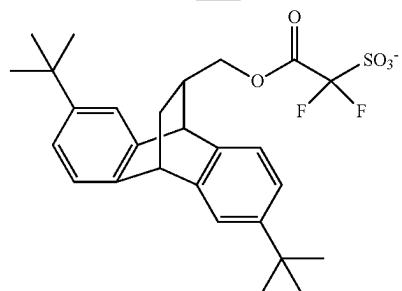
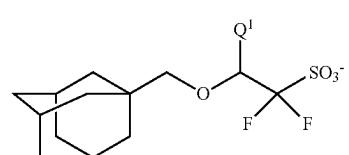
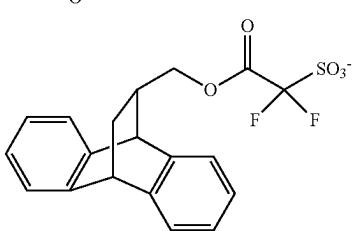
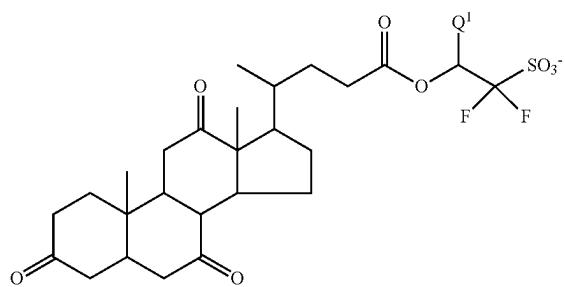
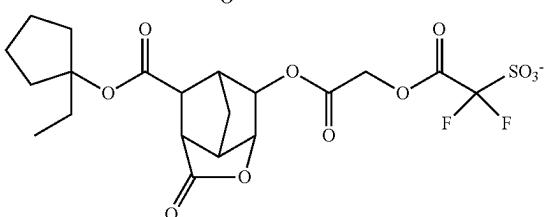
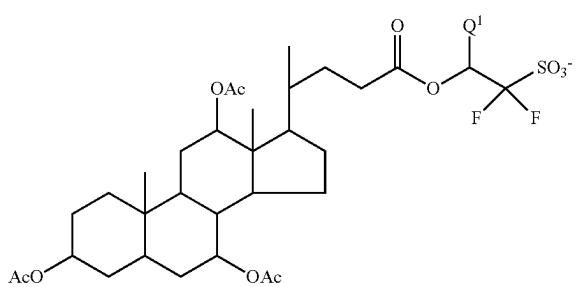
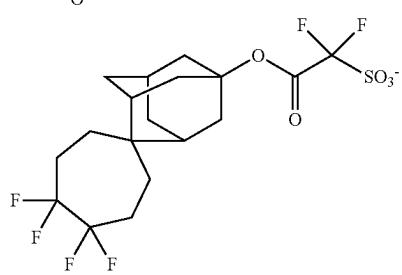
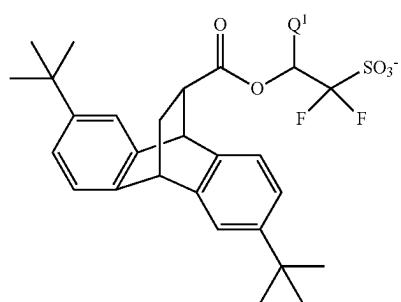
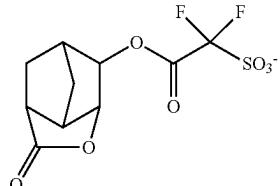
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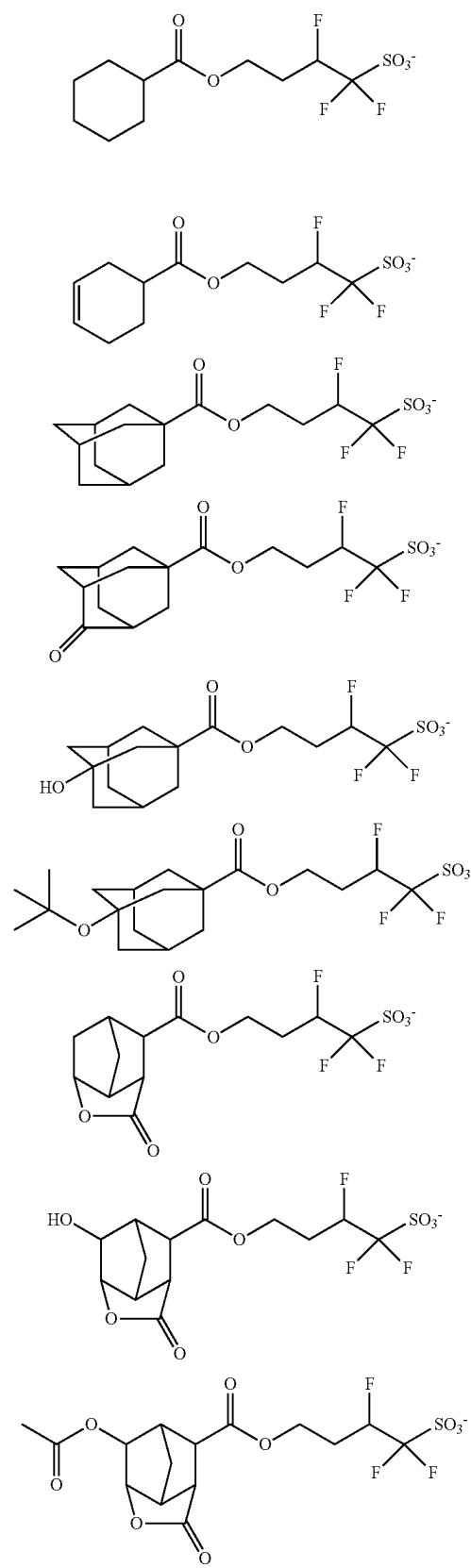
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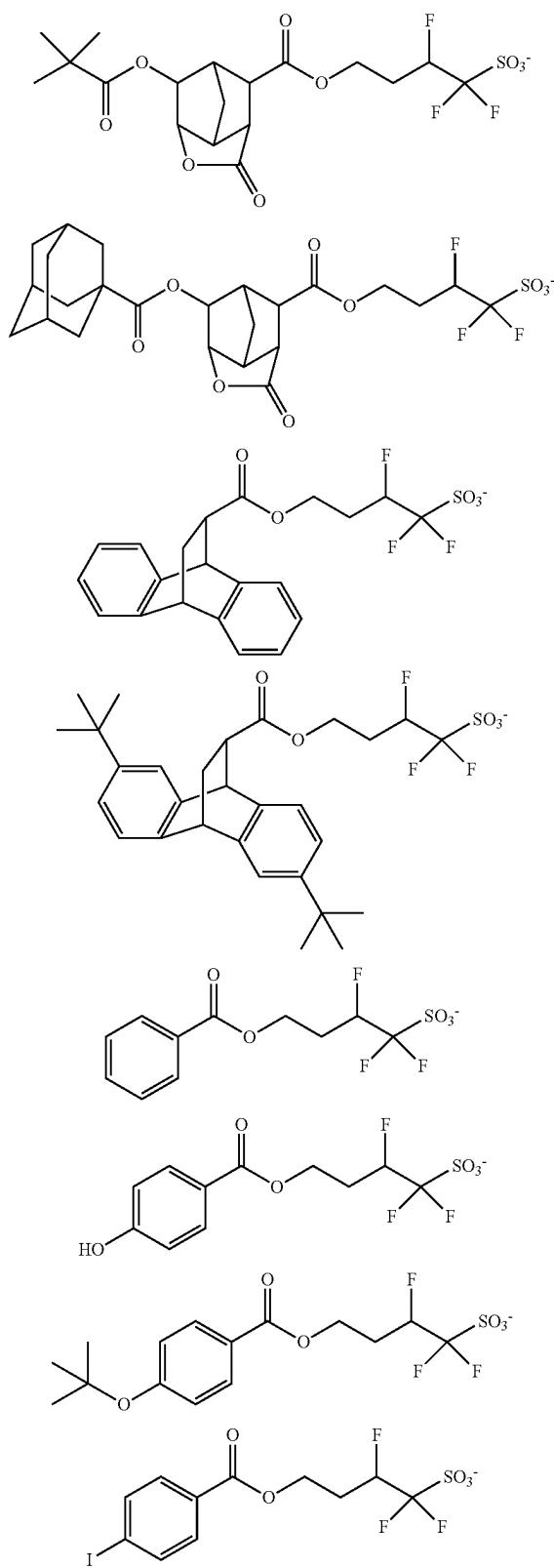
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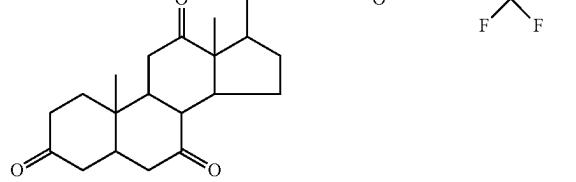
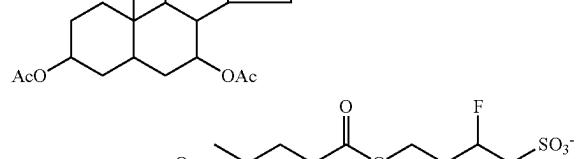
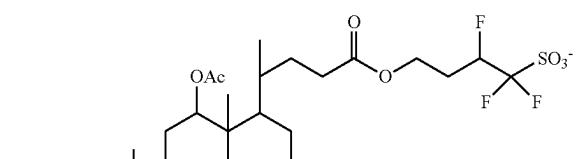
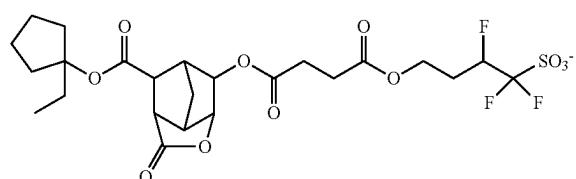
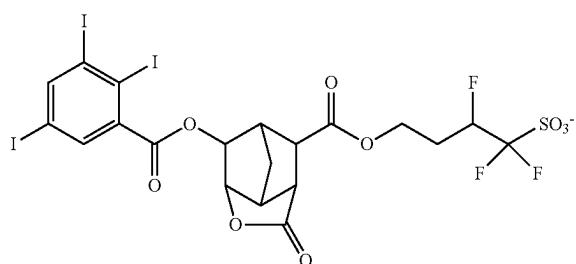
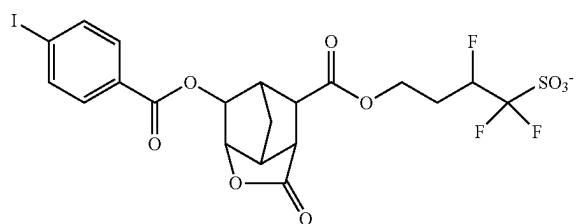
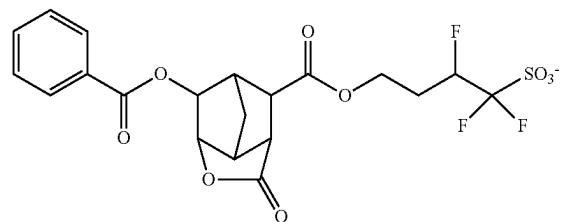
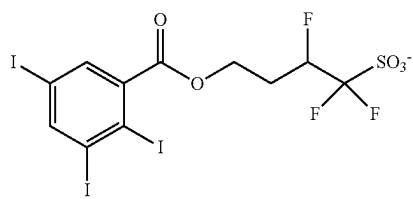
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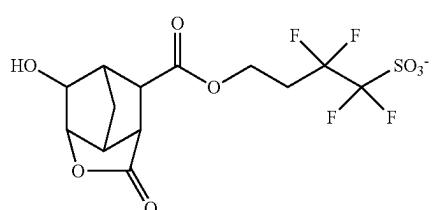
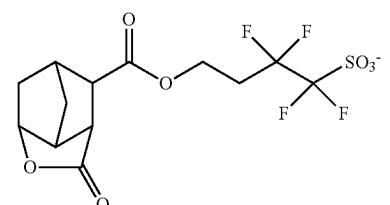
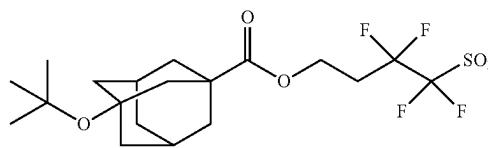
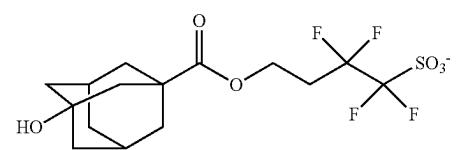
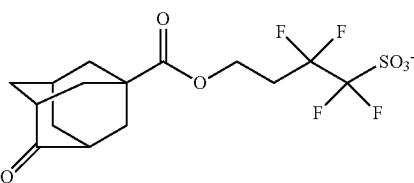
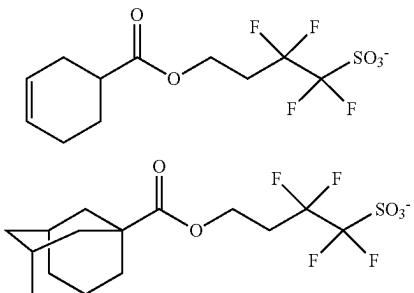
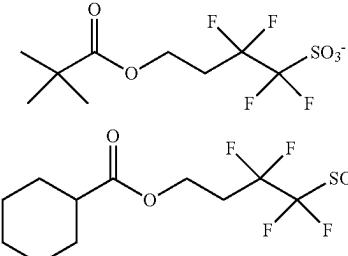
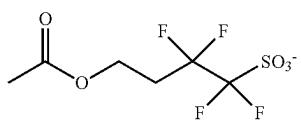
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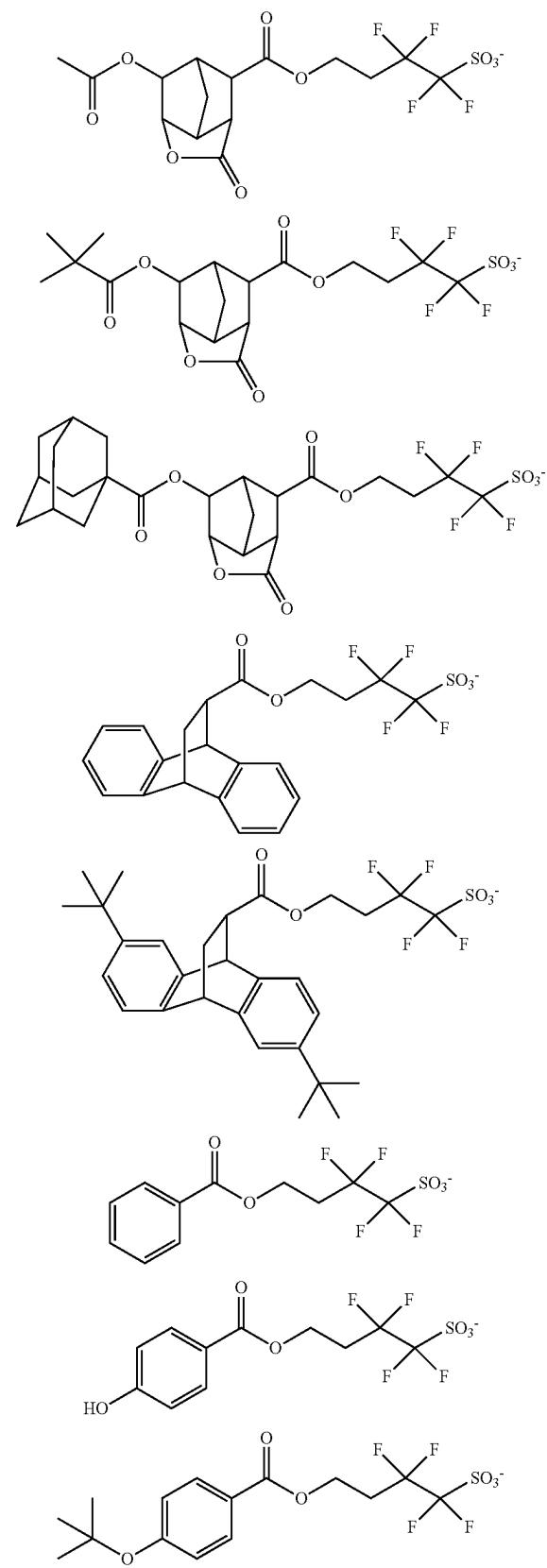
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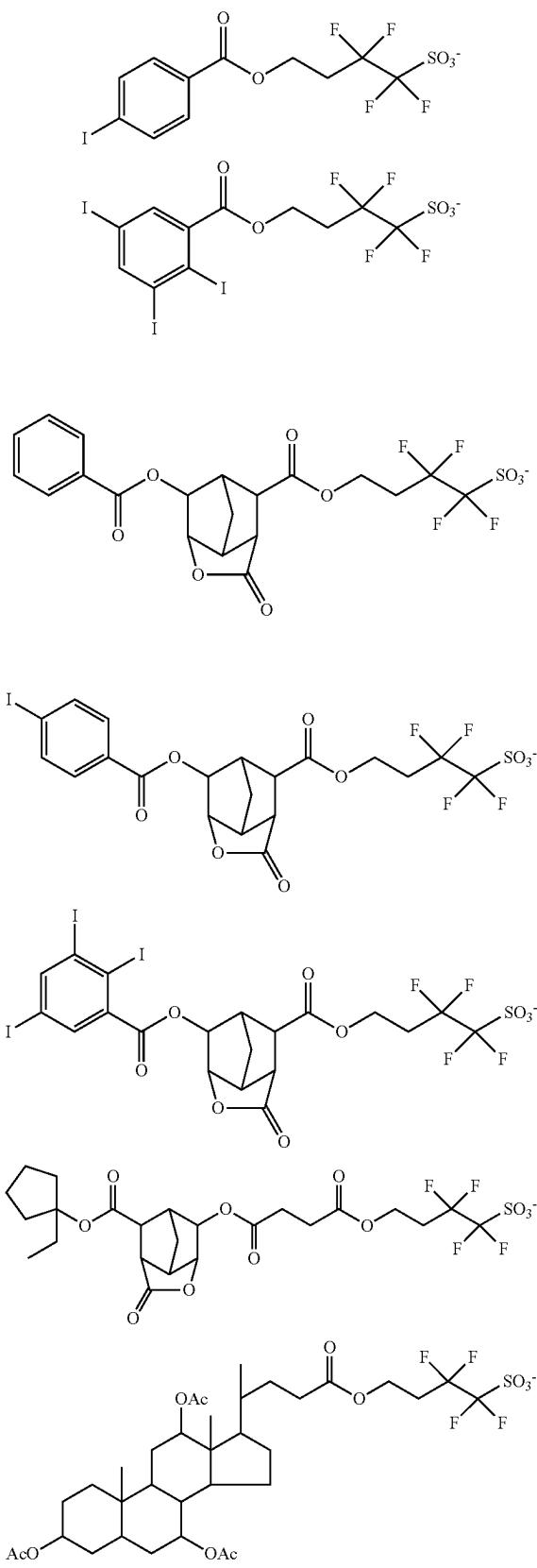
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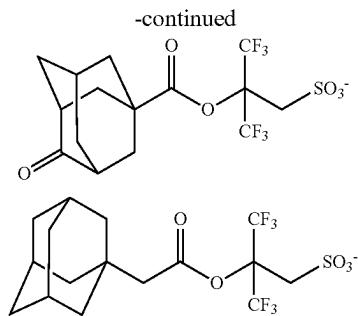
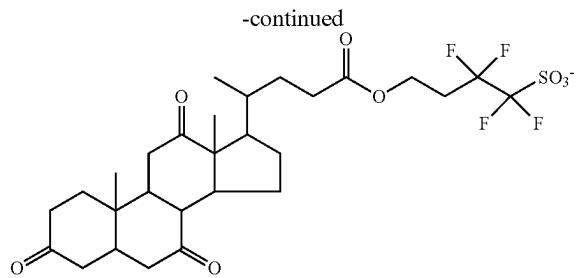


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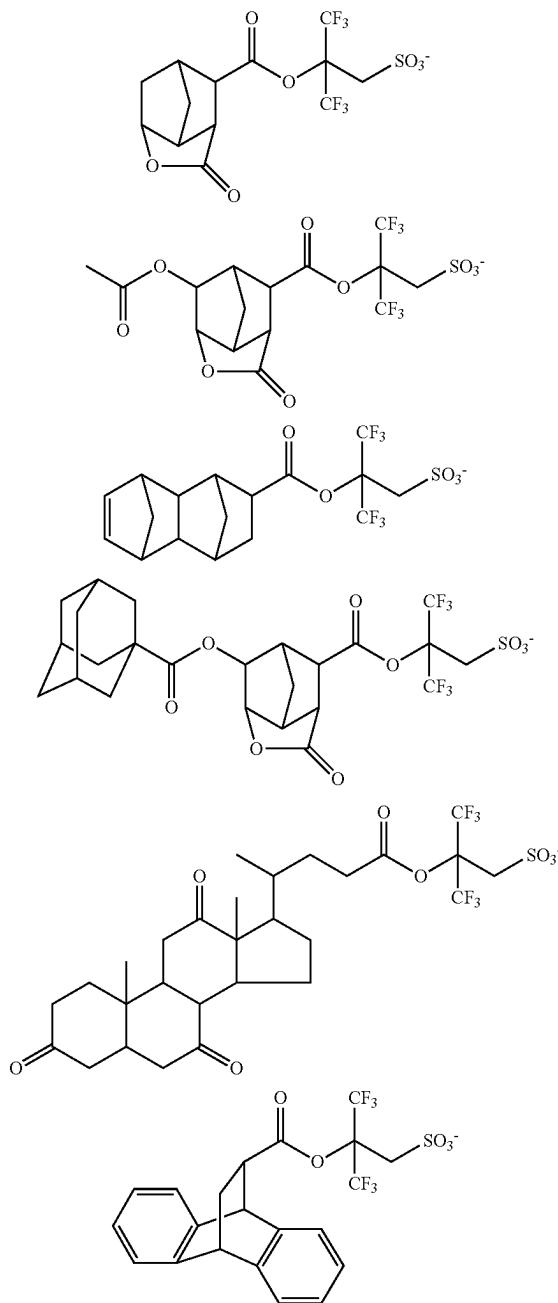
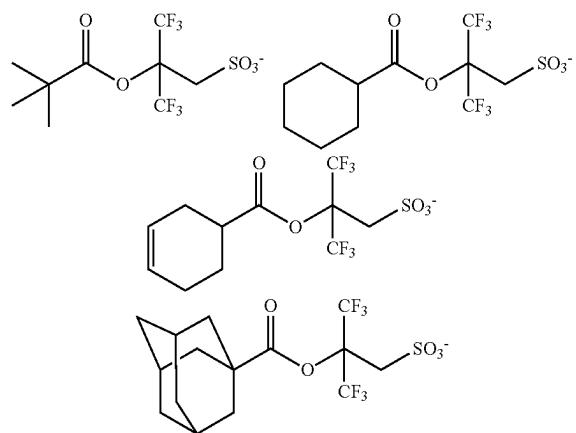


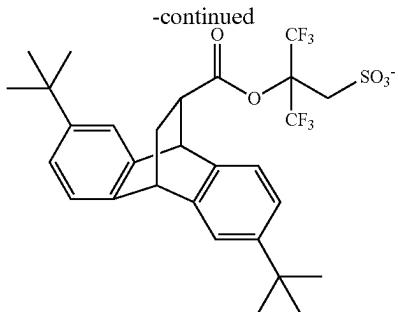
[0211] In formula (c1-2), R^{fb1} and R^{fb2} are each independently fluorine or a $\text{C}_1\text{-}\text{C}_{40}$ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for the hydrocarbyl group R^{fa1} in formula (c1-1-1). Preferably R^{fb1} and R^{fb2} are fluorine or $\text{C}_1\text{-}\text{C}_4$ straight fluorinated alkyl groups. Also, R^{fb1} and R^{fb2} may bond together to form a ring with the linkage: $-\text{CF}_2\text{-SO}_2\text{-N-SO}_2\text{-CF}_2-$ to which they are attached. It is preferred that a combination of R^{fb1} and R^{fb2} be a fluorinated ethylene or fluorinated propylene group.

[0212] In formula (c1-3), R^{fc1} , R^{fc2} and R^{fc3} are each independently fluorine or a $\text{C}_1\text{-}\text{C}_{40}$ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for the hydrocarbyl group R^{fa1} in formula (c1-1-1). Preferably R^{fc1} , R^{fc2} and R^{fc3} are fluorine or $\text{C}_1\text{-}\text{C}_4$ straight fluorinated alkyl groups. Also, R^{fc1} and R^{fc2} may bond together to form a ring with the linkage: $-\text{CF}_2\text{-SO}_2\text{-C-SO}_2\text{-CF}_2-$ to which they are attached. It is preferred that a combination of R^{fc1} and R^{fc2} be a fluorinated ethylene or fluorinated propylene group.

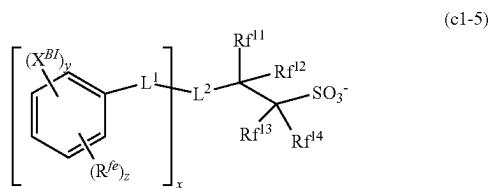
[0213] In formula (c1-4), R^{fd} is a $\text{C}_1\text{-}\text{C}_{40}$ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for R^{fa1} .

[0214] Examples of the anion having formula (c1-4) are shown below, but not limited thereto.





[0215] Anions having an iodized or brominated aromatic ring are also useful as the non-nucleophilic counter ion. These anions have the formula (c1-5).



[0216] In formula (c1-5), x is an integer of 1 to 3, y is an integer of 1 to 5, z is an integer of 0 to 3, and y+z is from 1 to 5. Preferably, y is 1, 2 or 3, more preferably 2 or 3, and z is 0, 1 or 2.

[0217] X^{BI} is iodine or bromine. A plurality of X^{BI} may be identical or different when x and/or y is 2 or more.

[0218] L^1 is a single bond, ether bond, ester bond, or a C_1-C_6 saturated hydrocarbylene group which may contain an ether bond or ester bond. The saturated hydrocarbylene group may be straight, branched or cyclic.

[0219] L^2 is a single bond or a C_1-C_{20} divalent linking group when x=1, or a C_1-C_{20} ($x+1$)-valent linking group when x=2 or 3. The linking group may contain an oxygen, sulfur or nitrogen atom.

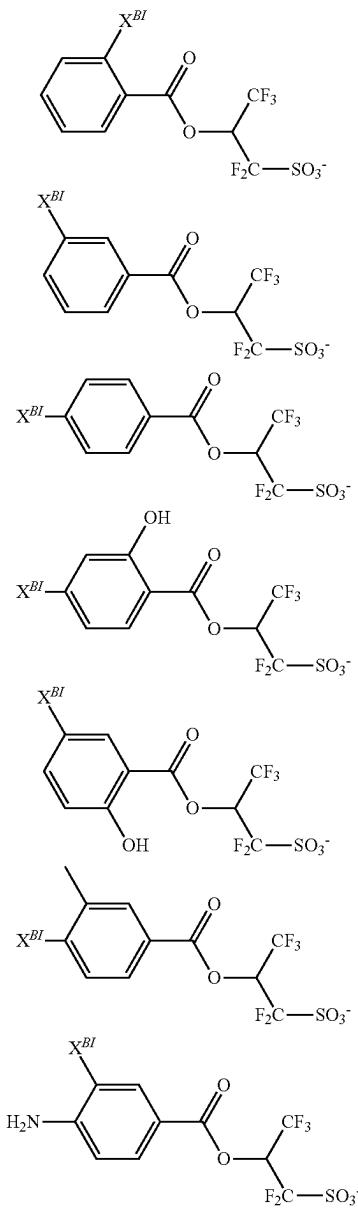
[0220] R^{fe} is hydroxy, carboxy, fluorine, chlorine, bromine, amino group, or a C_1-C_{20} hydrocarbyl, C_1-C_{20} hydrocarbyloxy, C_2-C_{20} hydrocarbylcarbonyl, C_2-C_{20} hydrocarbyloxycarbonyl, C_2-C_{20} hydrocarbylcarbonyloxy, or C_1-C_{20} hydrocarbylsulfonyloxy group, which may contain fluorine, chlorine, bromine, hydroxy, amino or ether bond, or $-N(R^{feA})(R^{feB})$, $-N(R^{feC})-C(=O)-R^{feD}$ or $-N(R^{feC})-C(=O)-O-R^{feD}$. R^{feA} and R^{feB} are each independently hydrogen or a C_1-C_6 saturated hydrocarbyl group. R^{feC} is hydrogen, or a C_1-C_6 saturated hydrocarbyl group which may contain halogen, hydroxy, C_1-C_6 saturated hydrocarbyloxy, C_2-C_6 saturated hydrocarbylcarbonyl or C_2-C_6 saturated hydrocarbyloxycarbonyloxy moiety. The aliphatic hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. The hydrocarbyl, hydrocarbyloxy, hydrocarbylcarbonyl, hydrocarbyloxycarbonyl, hydrocarbylcarbonyloxy, and hydrocarbylsulfony-

loxy groups may be straight, branched or cyclic. A plurality of R^{fe} may be identical or different when x and/or z is 2 or more.

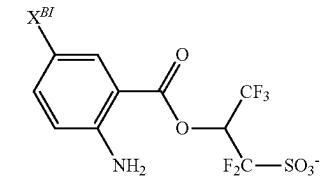
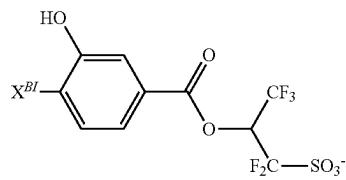
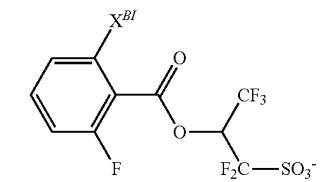
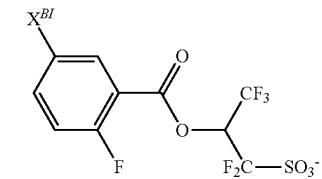
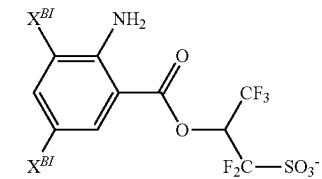
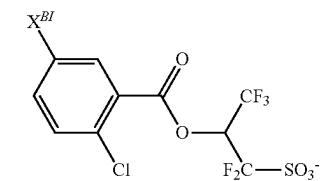
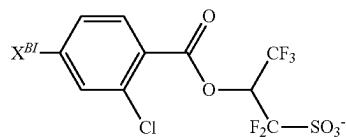
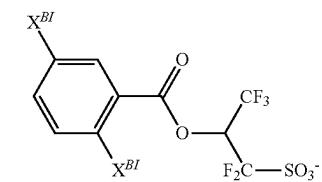
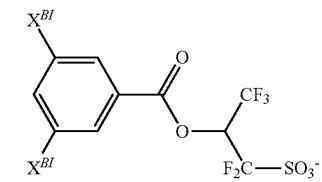
[0221] Of these, R^{fe} is preferably hydroxy, $-N(R^{feC})-C(=O)-R^{feD}-N(R^{feC})-C(=O)-O-R^{feD}$, fluorine, chlorine, bromine, methyl or methoxy.

[0222] R^{f11} to R^{f14} are each independently hydrogen, fluorine or trifluoromethyl, at least one of R^{f11} to R^{f14} is fluorine or trifluoromethyl. R^{f11} and R^{f12} , taken together, may form a carbonyl group. More preferably, both R^{f13} and R^{f14} are fluorine.

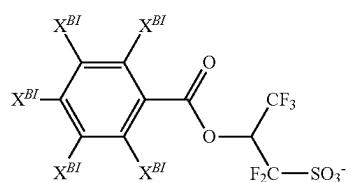
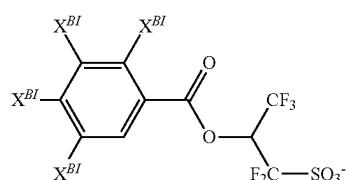
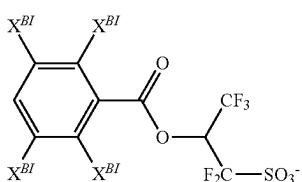
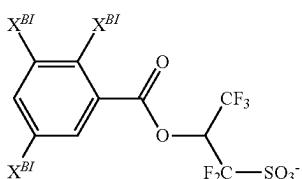
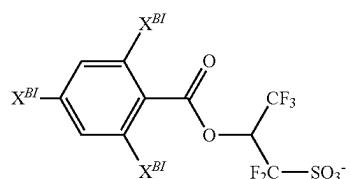
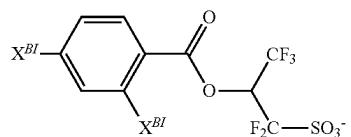
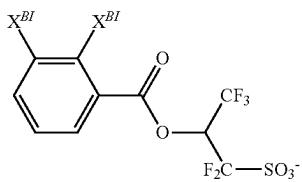
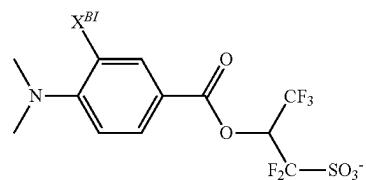
[0223] Examples of the anion having formula (c1-5) are shown below, but not limited thereto. X^{BI} is as defined above.



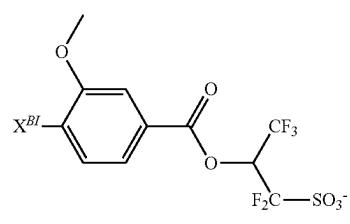
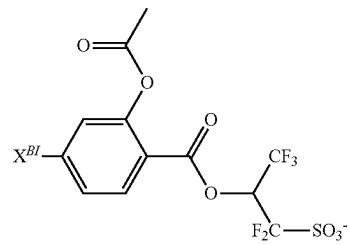
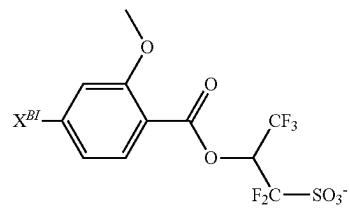
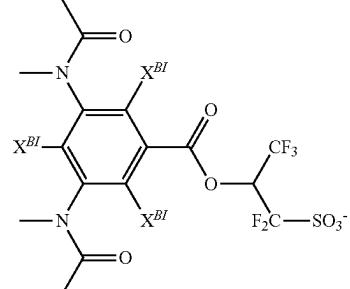
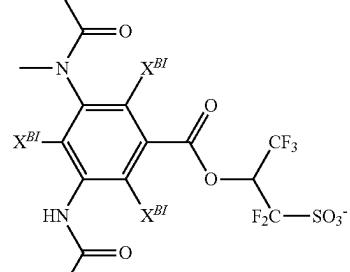
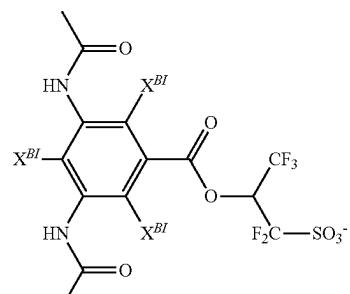
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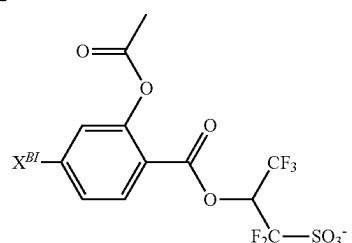
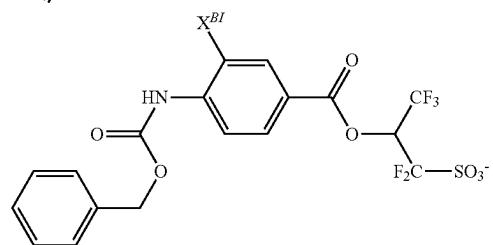
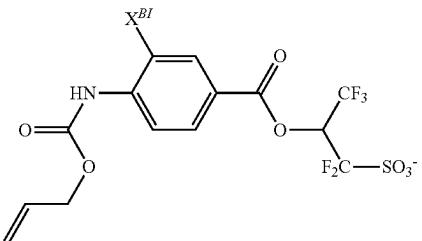
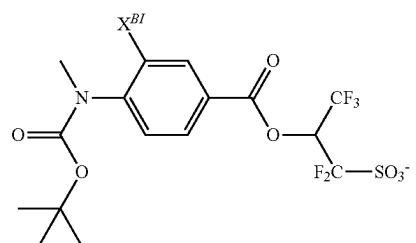
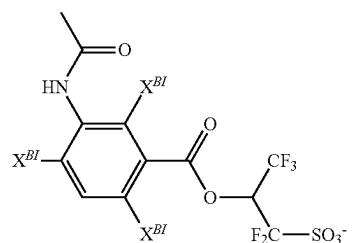
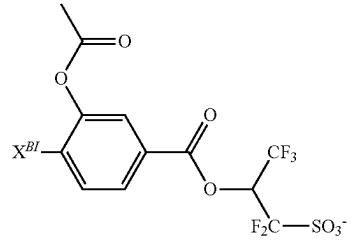
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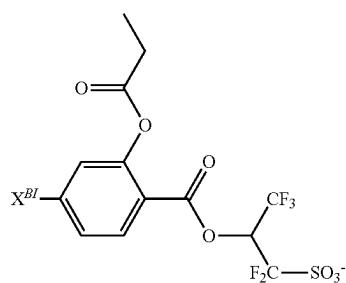
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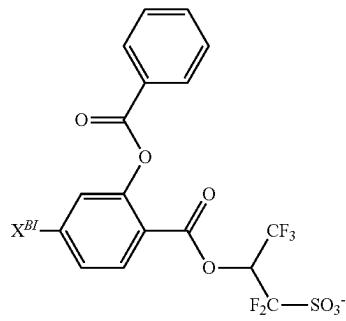
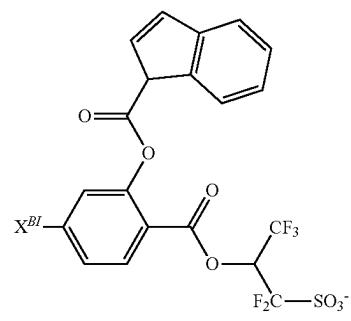
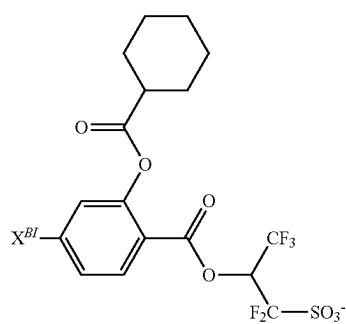
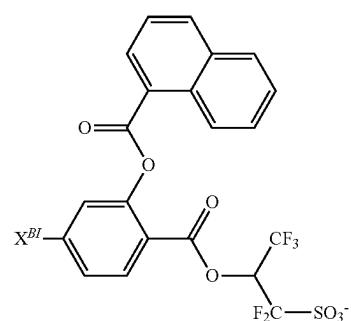
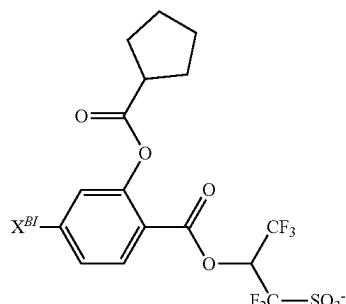
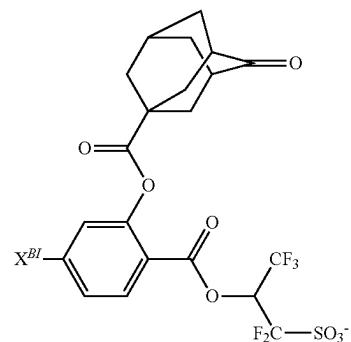
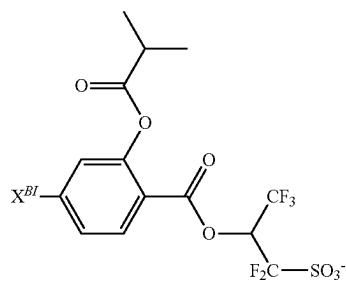
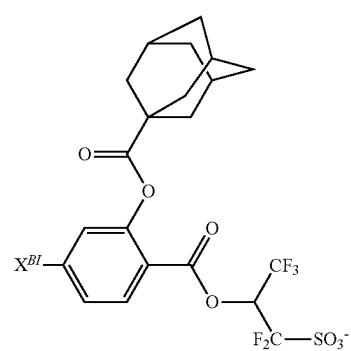
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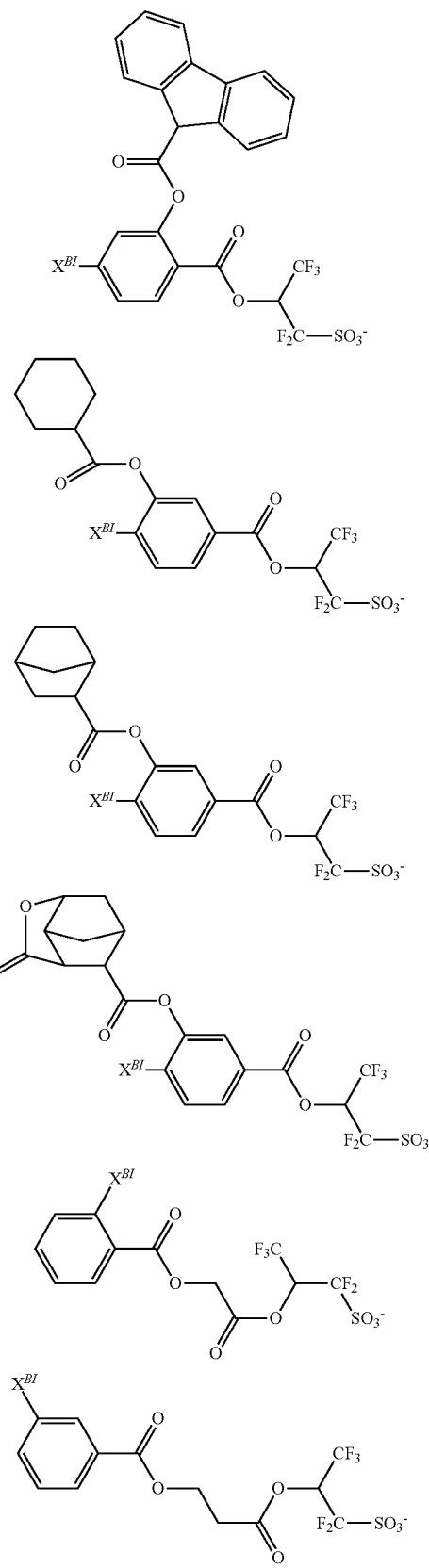
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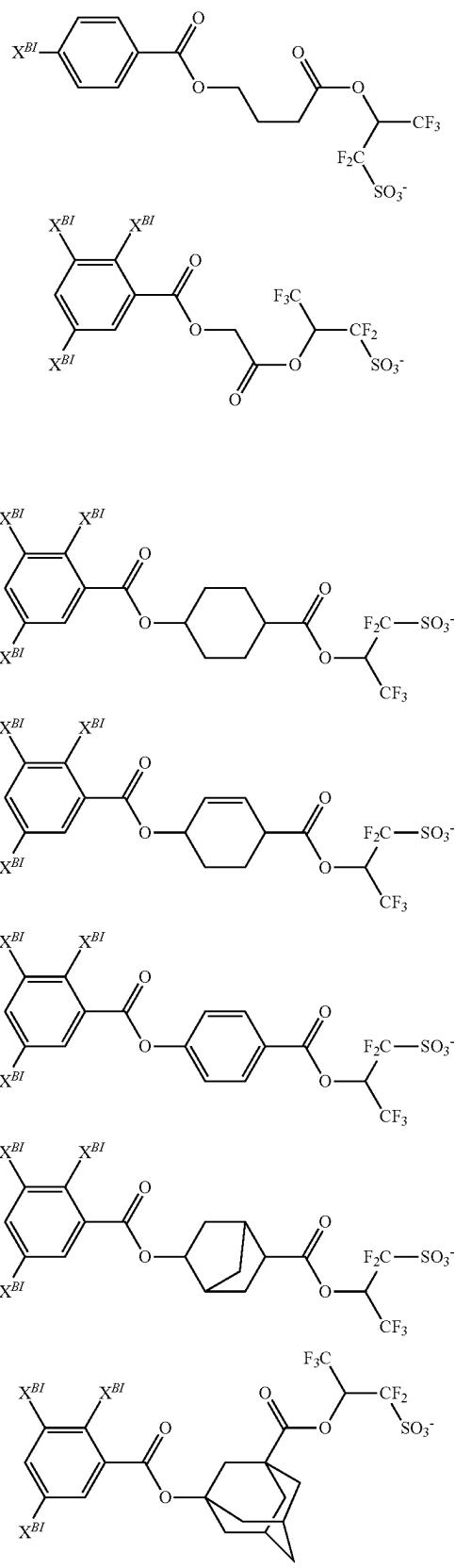
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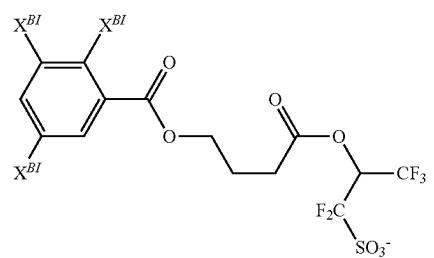
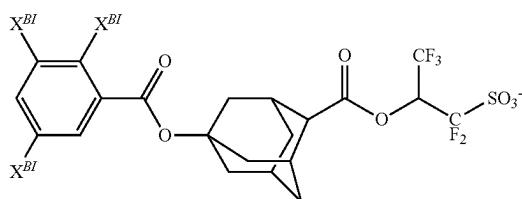
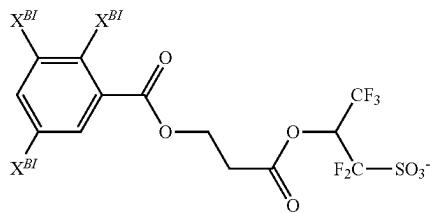
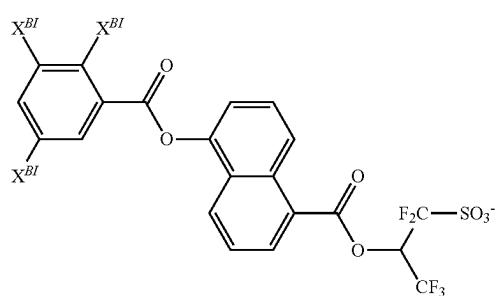
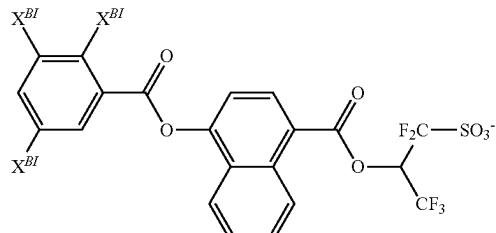
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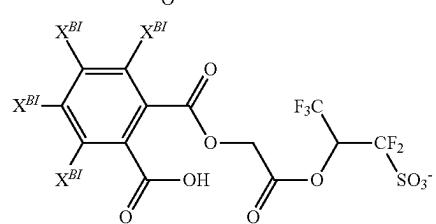
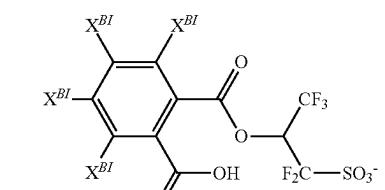
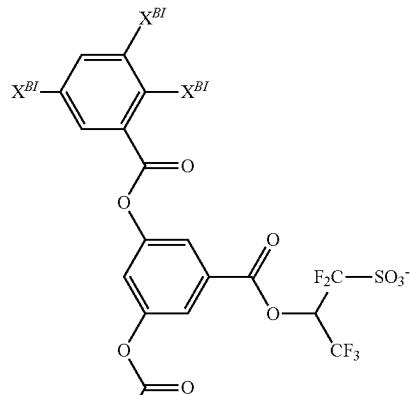
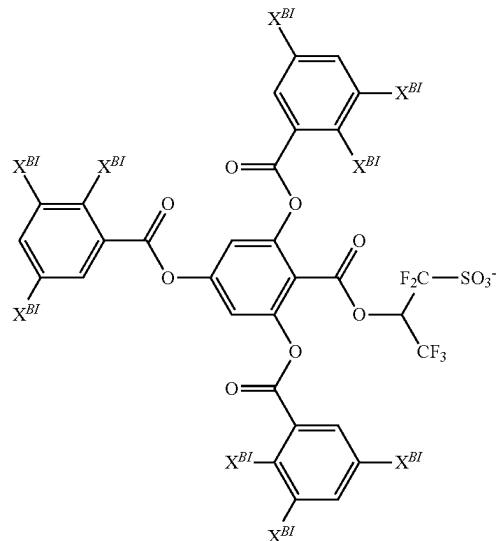
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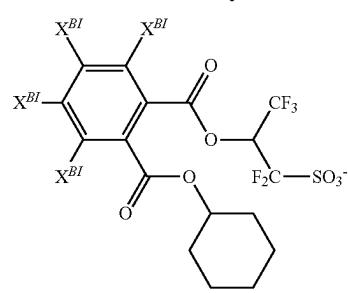
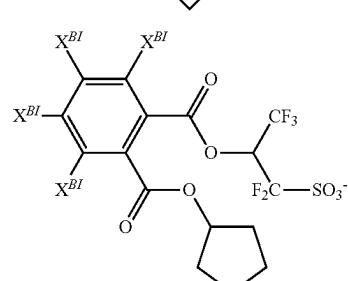
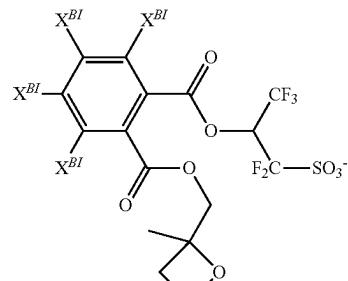
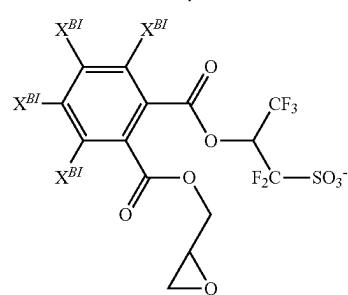
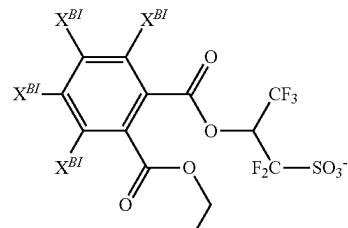
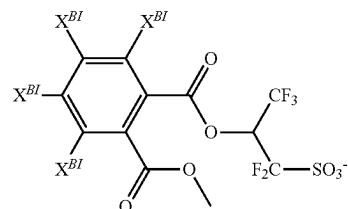
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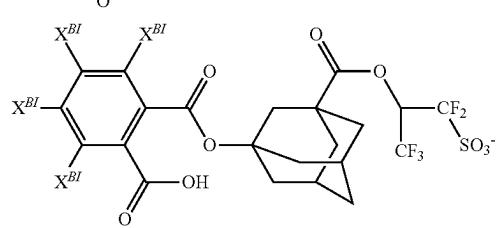
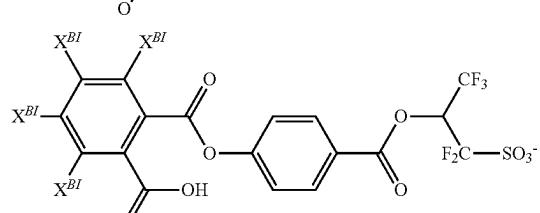
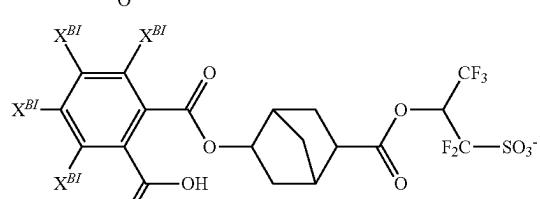
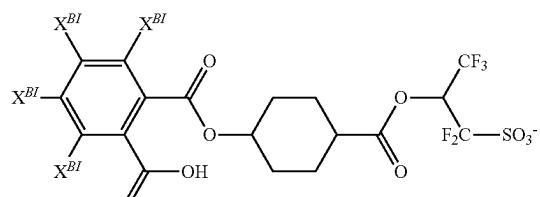
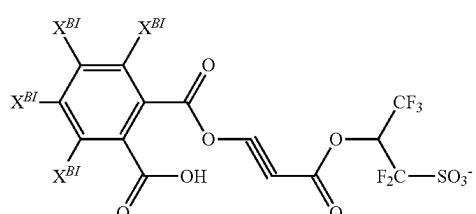
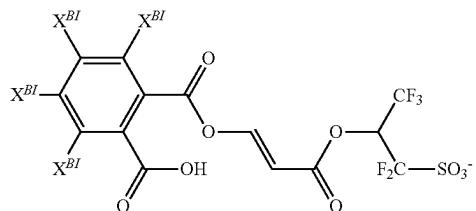
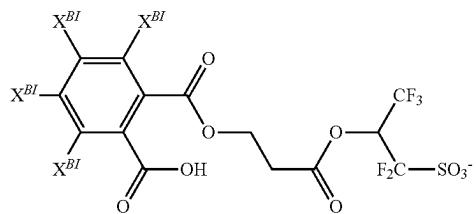
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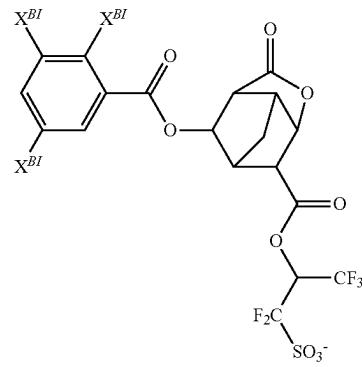
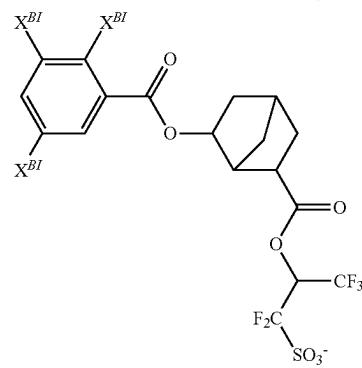
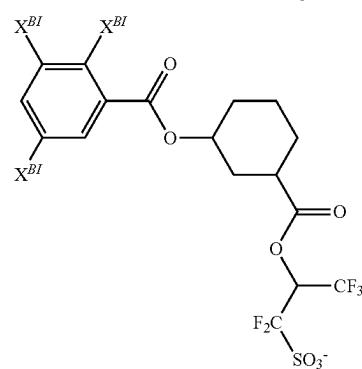
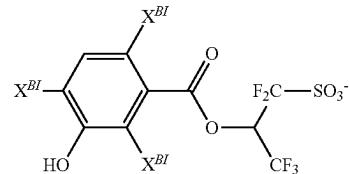
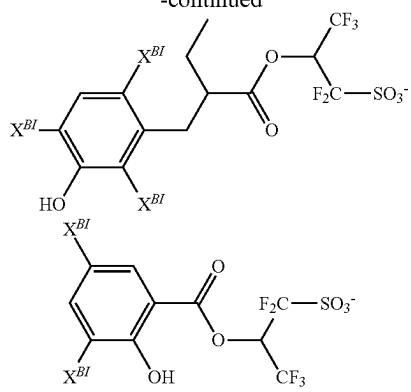
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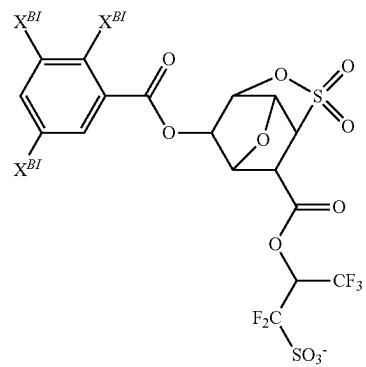
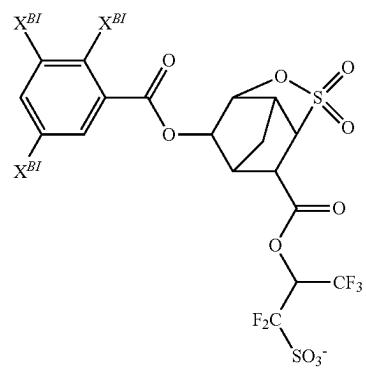
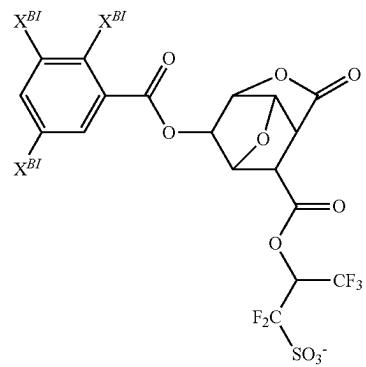
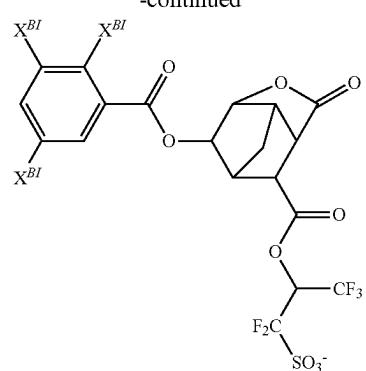
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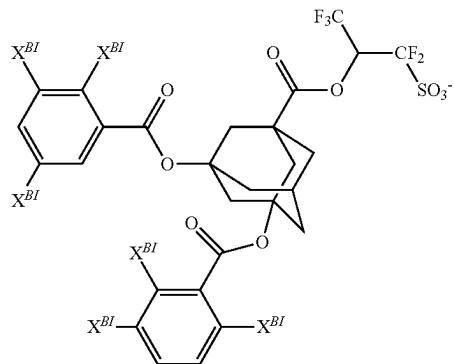
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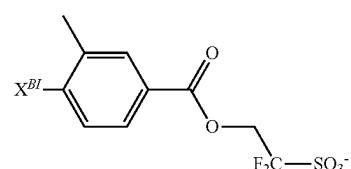
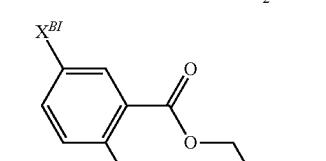
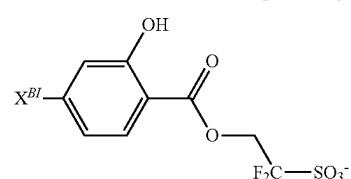
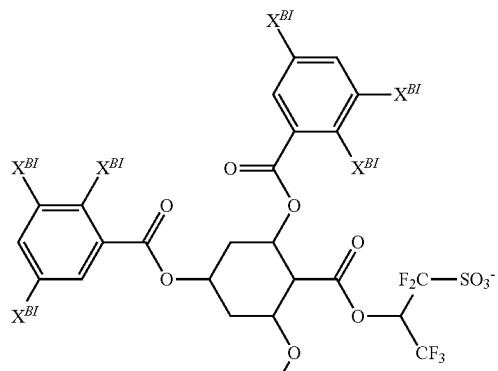
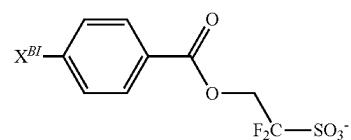
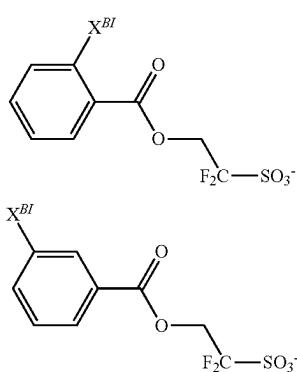
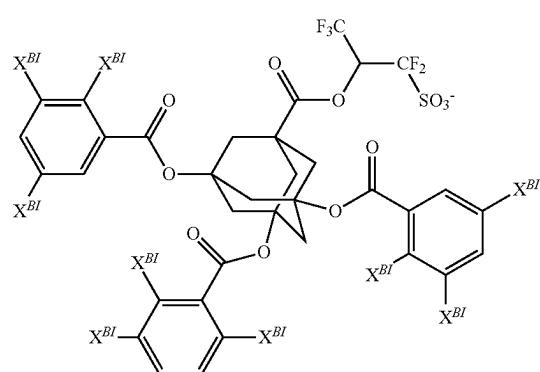
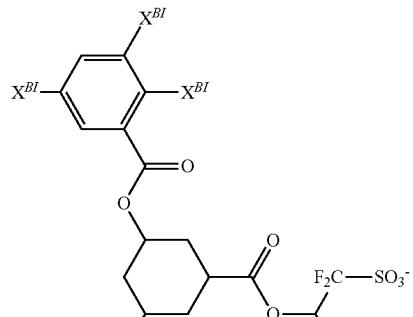
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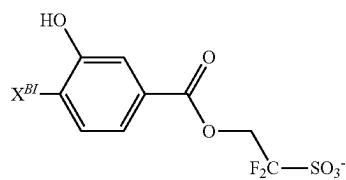
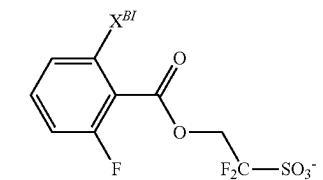
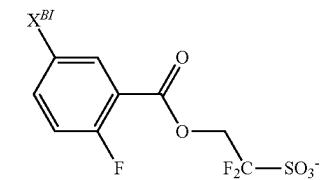
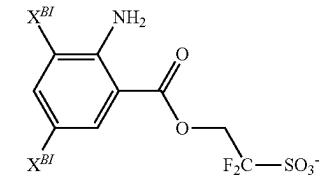
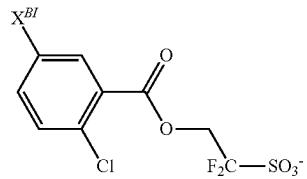
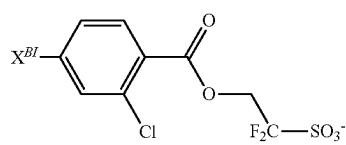
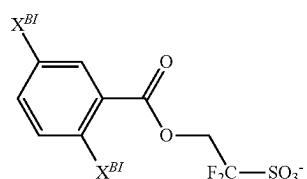
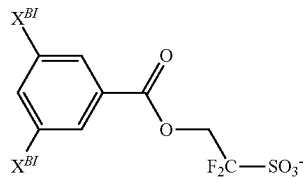
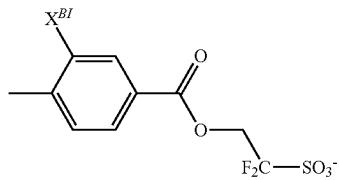
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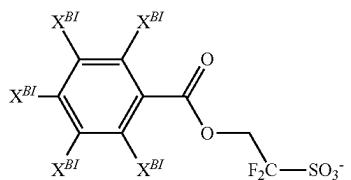
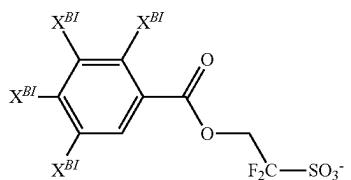
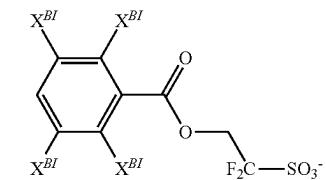
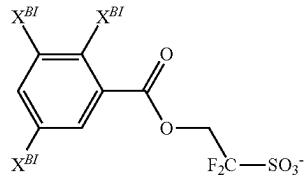
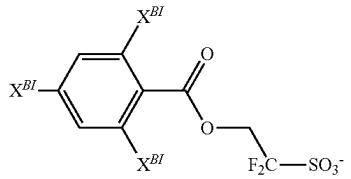
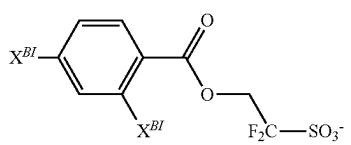
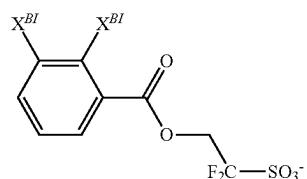
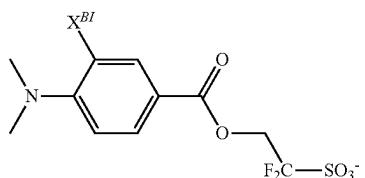
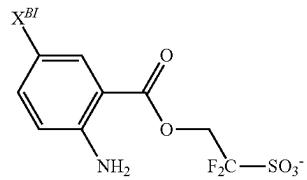
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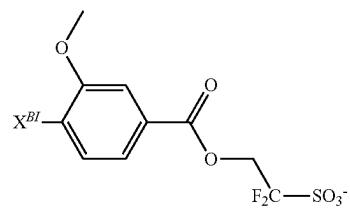
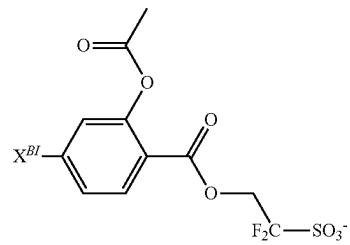
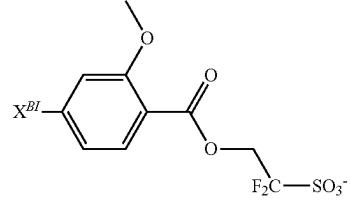
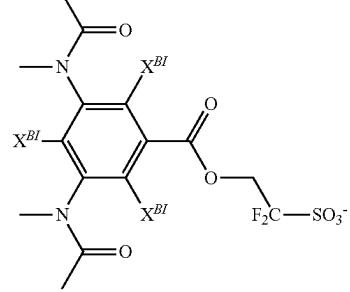
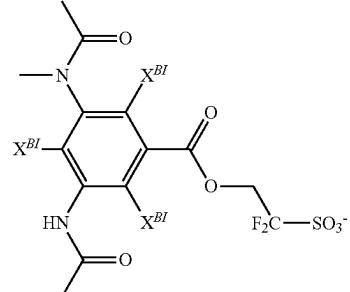
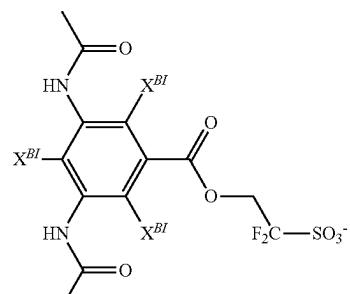
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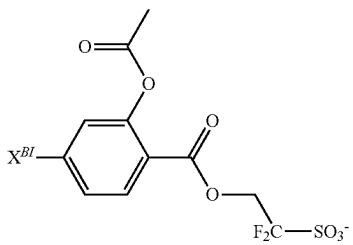
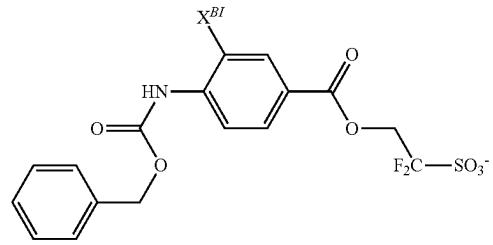
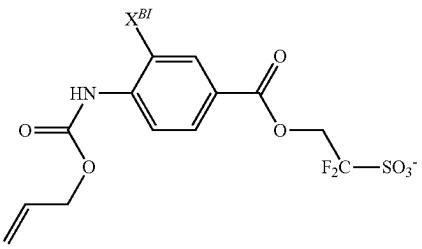
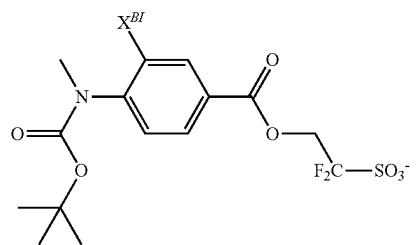
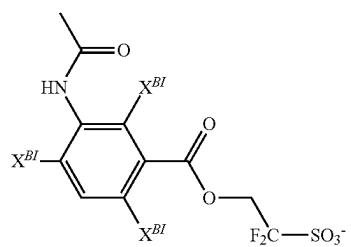
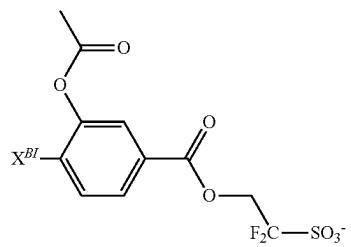
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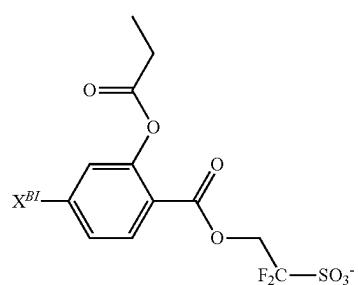
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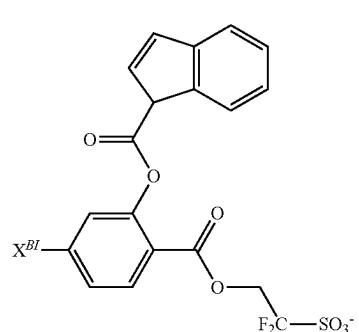
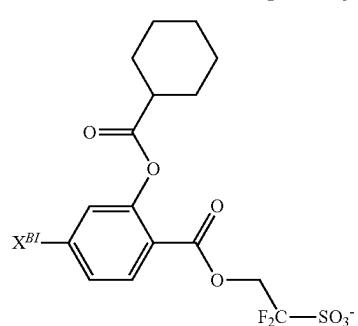
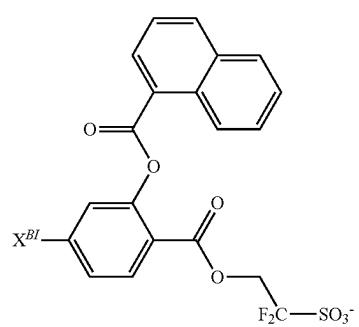
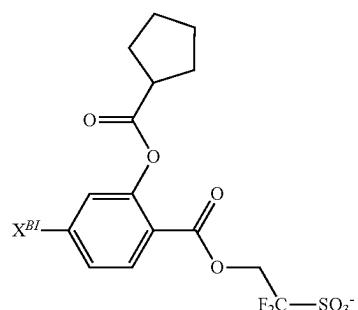
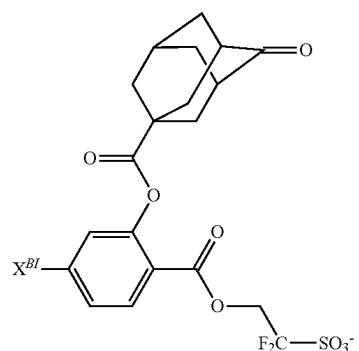
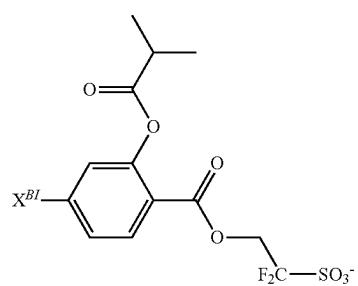
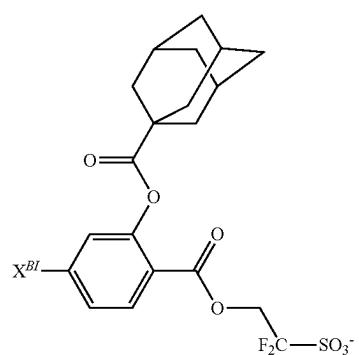
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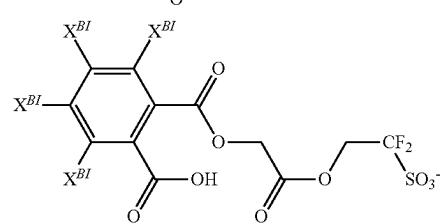
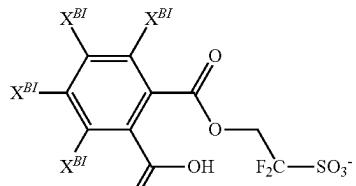
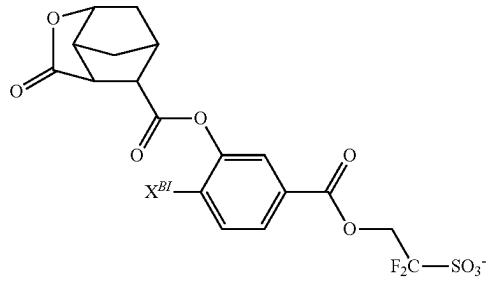
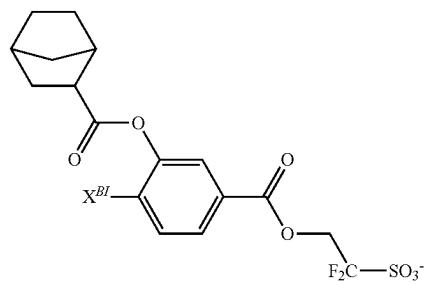
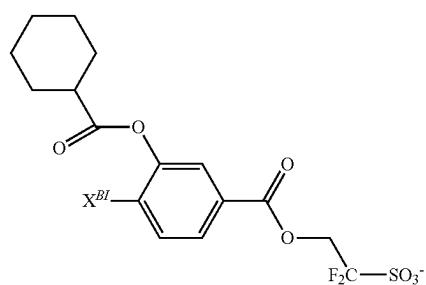
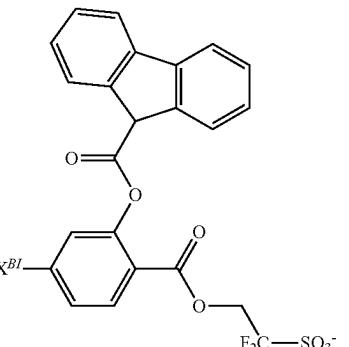
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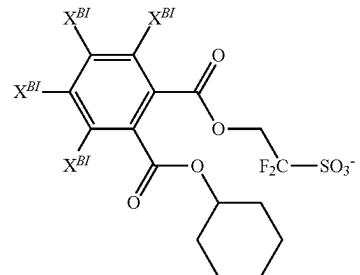
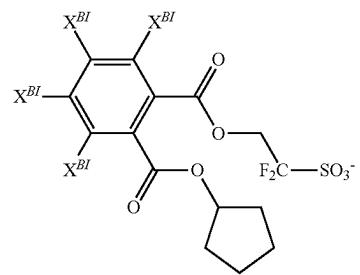
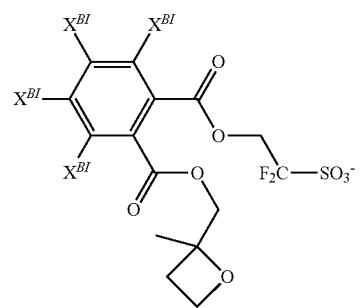
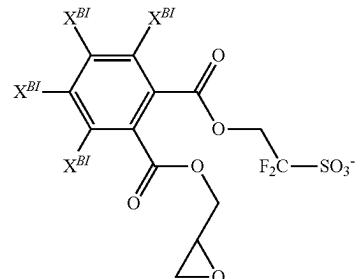
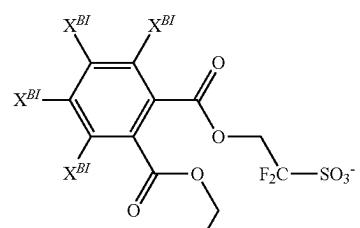
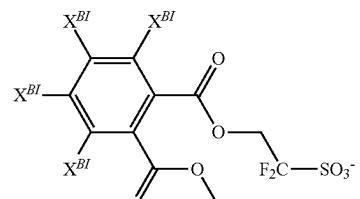
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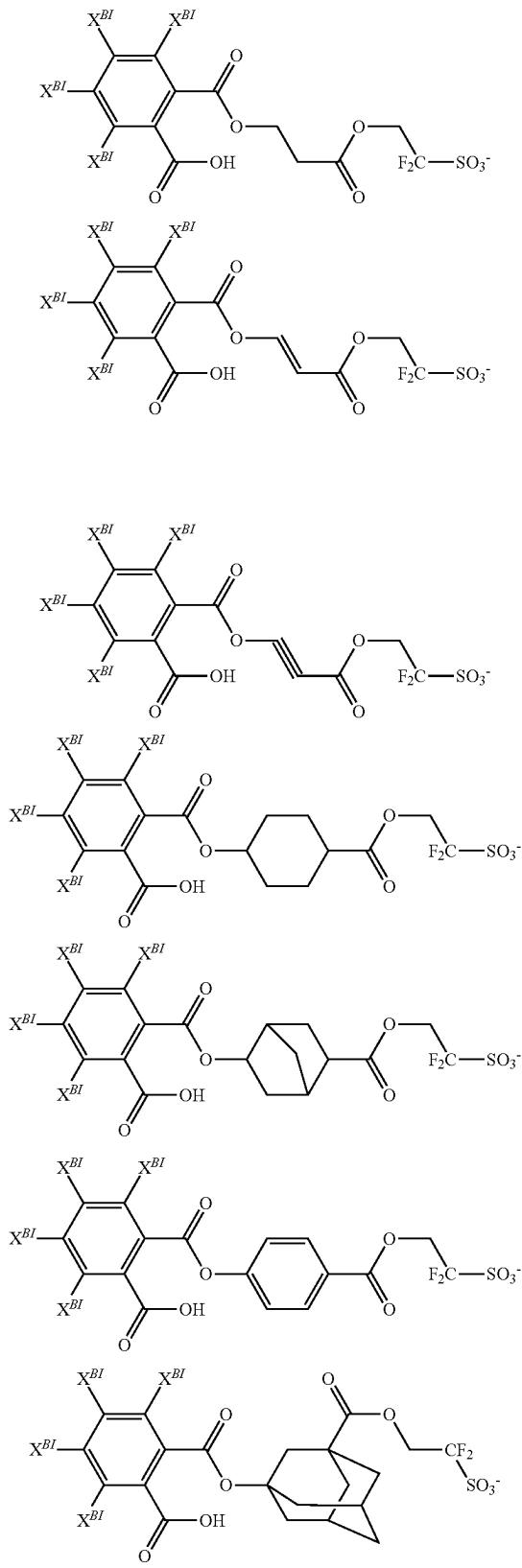
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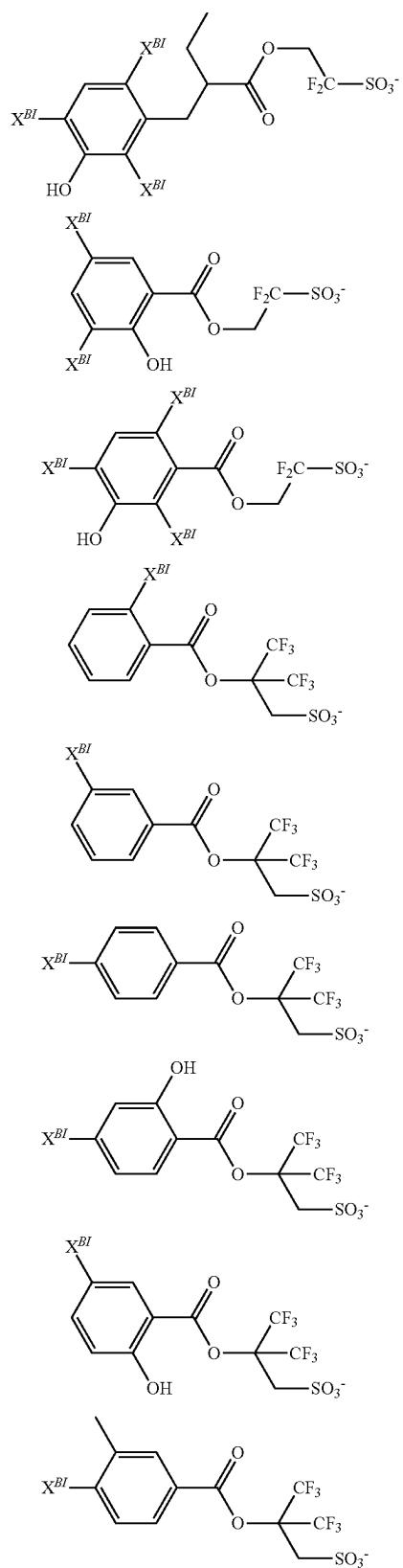
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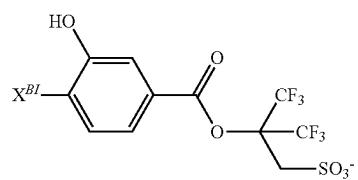
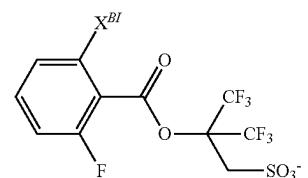
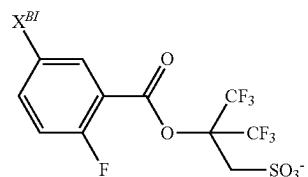
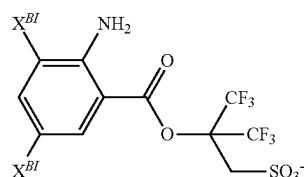
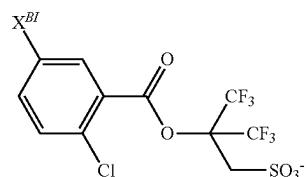
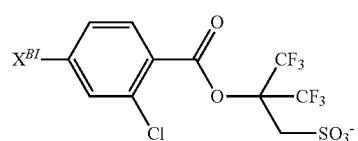
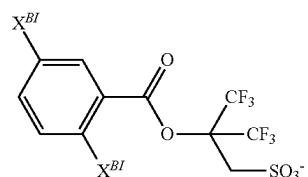
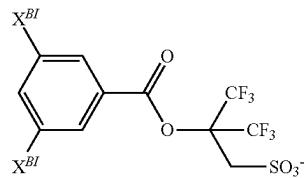
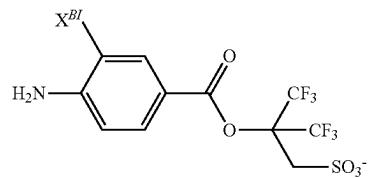
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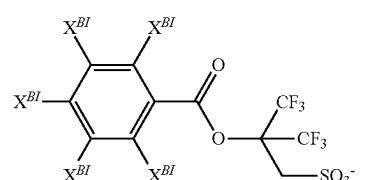
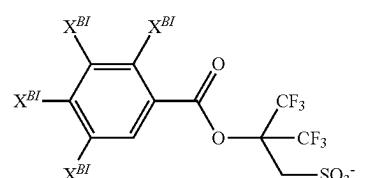
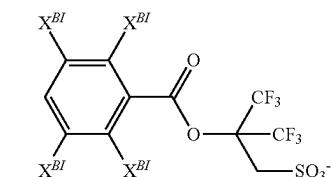
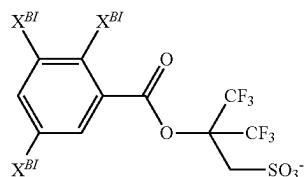
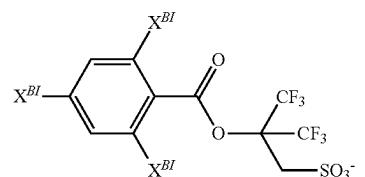
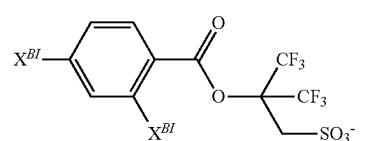
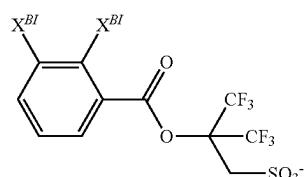
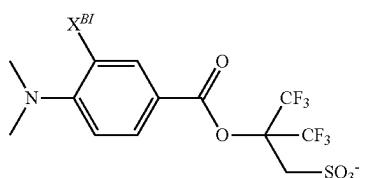
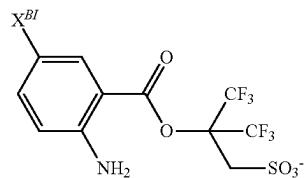
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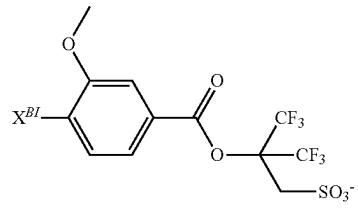
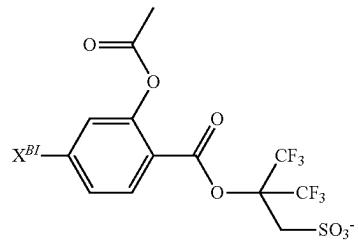
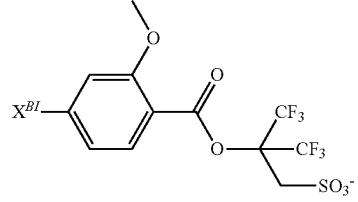
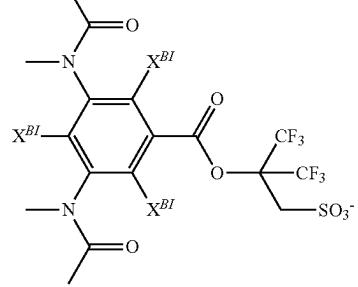
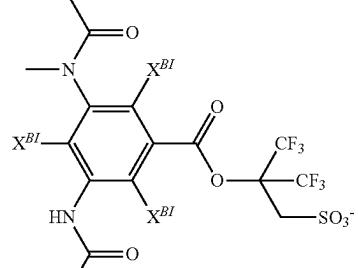
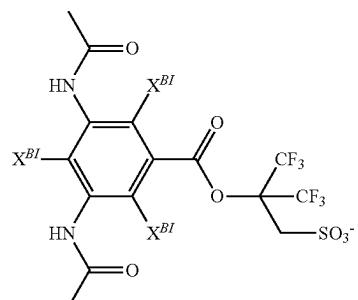
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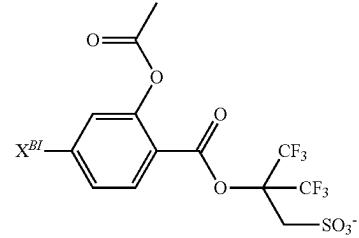
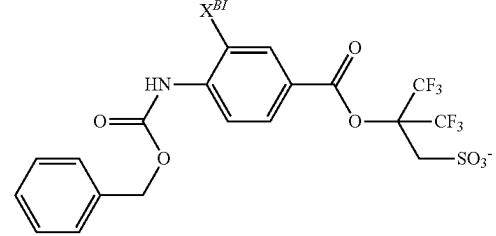
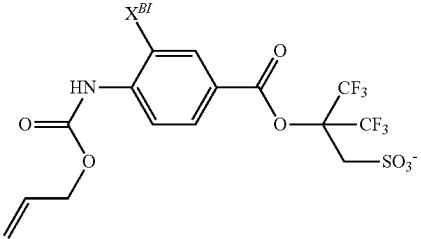
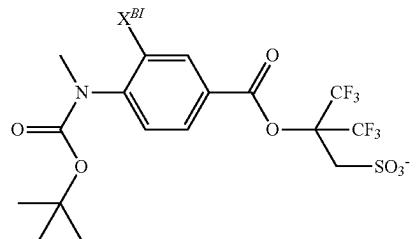
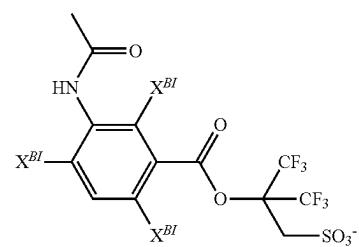
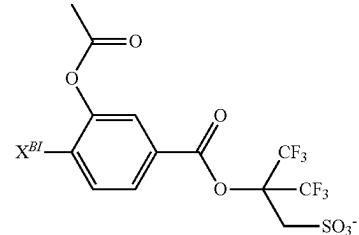
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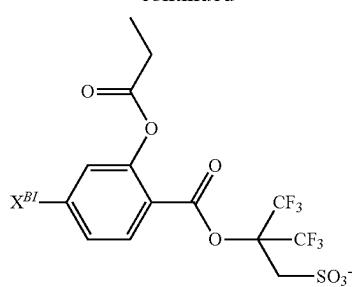
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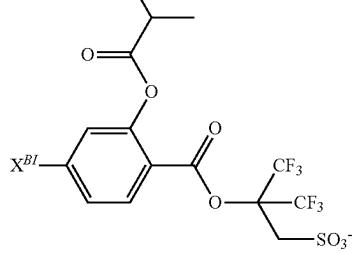
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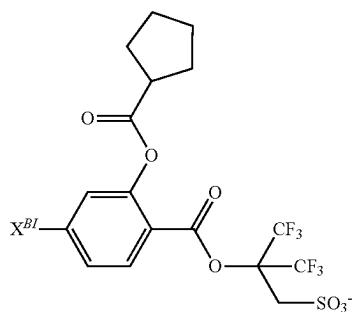
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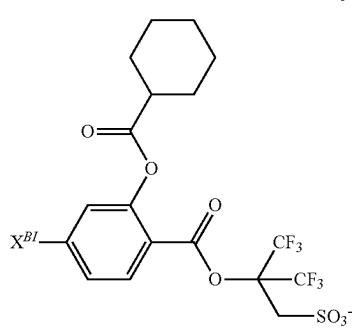
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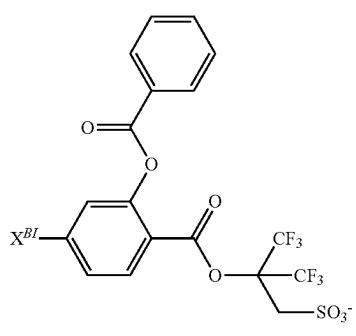
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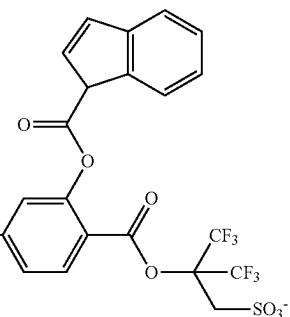
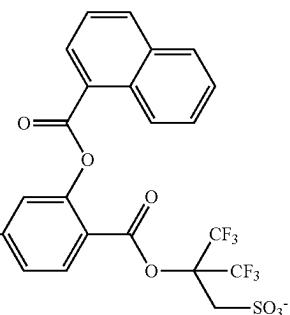
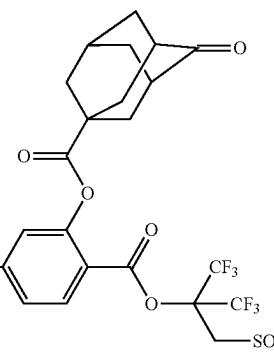
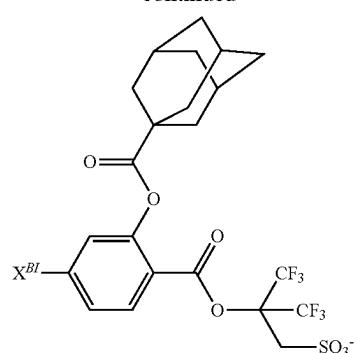
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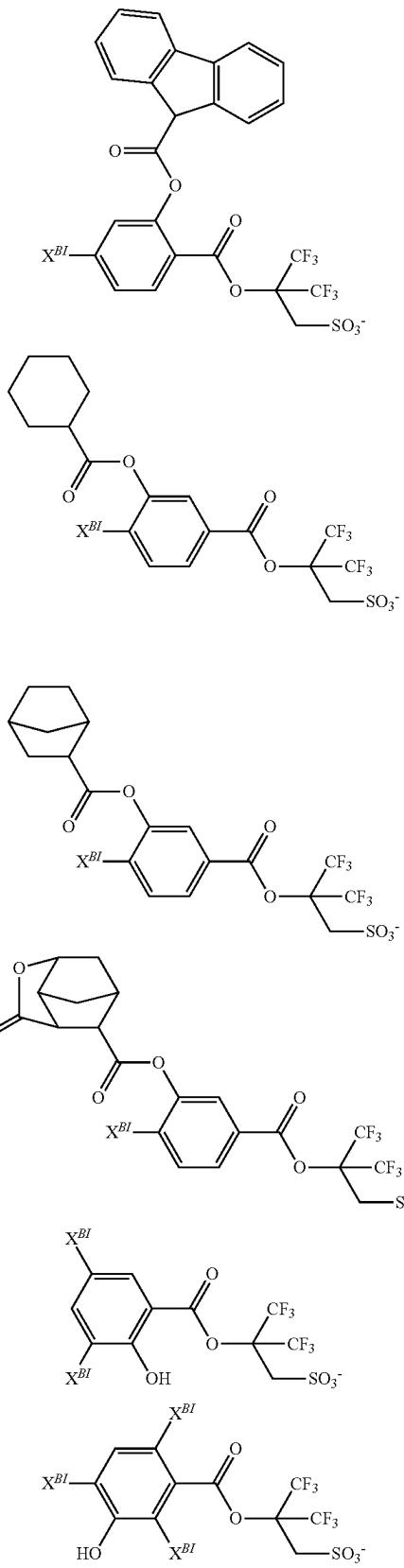
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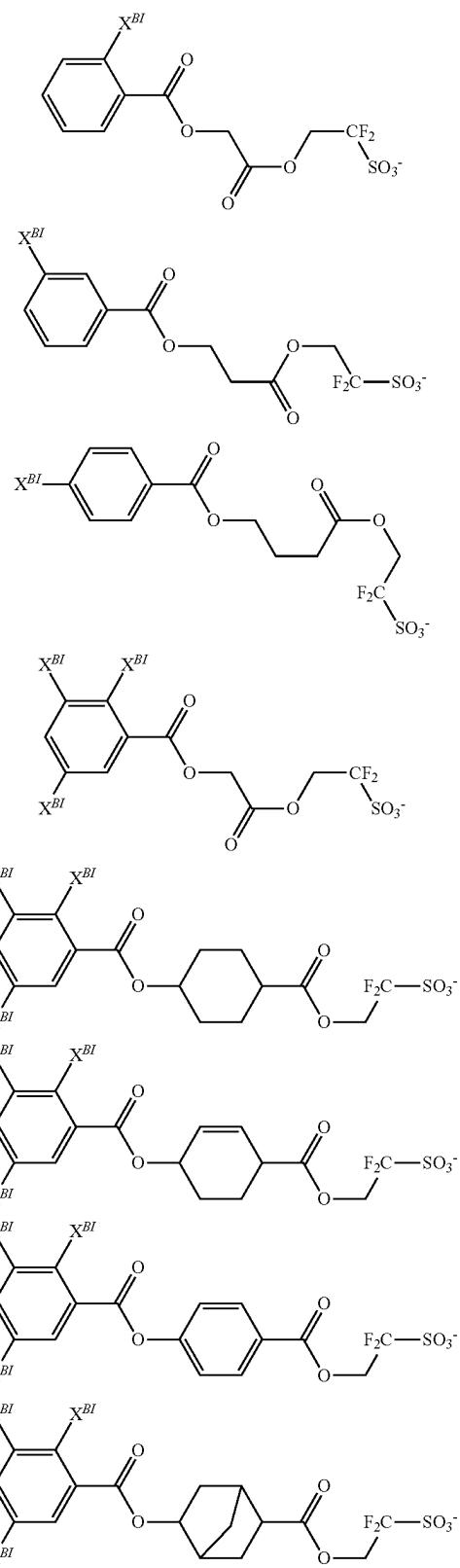
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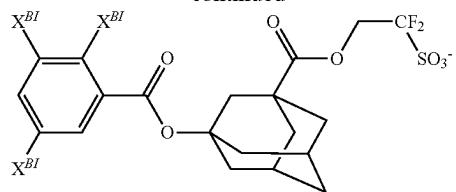
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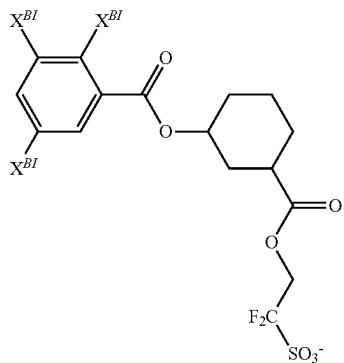
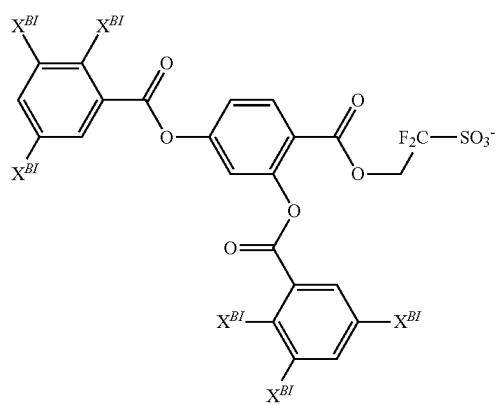
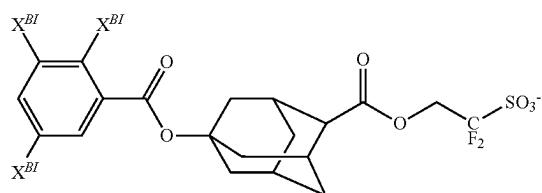
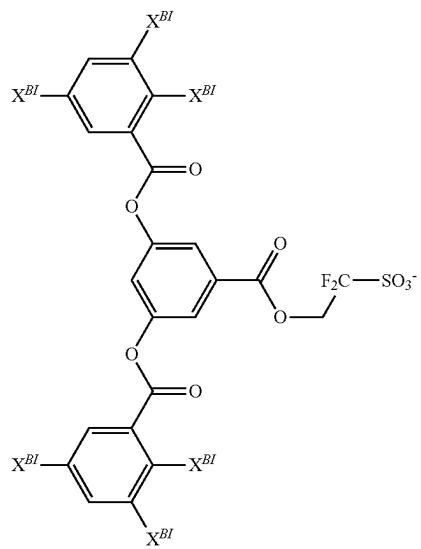
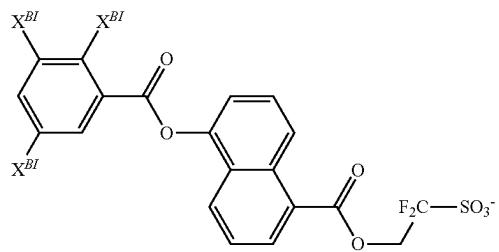
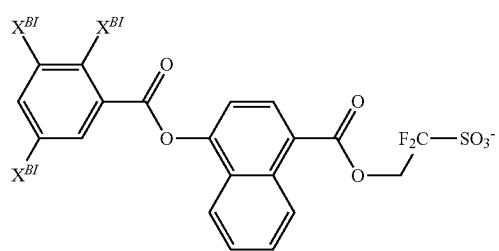
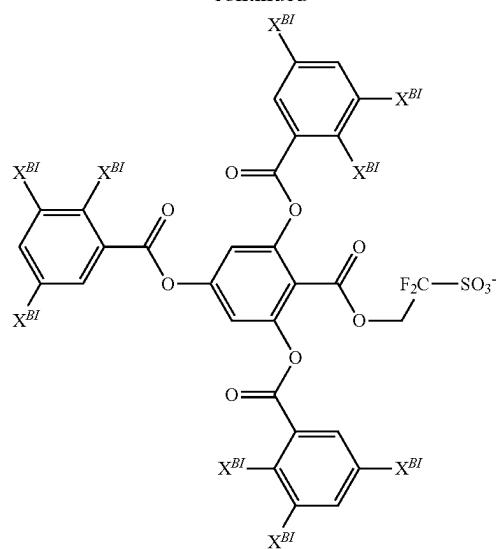
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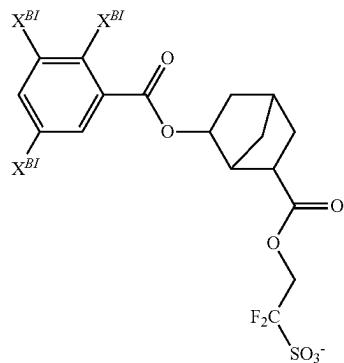
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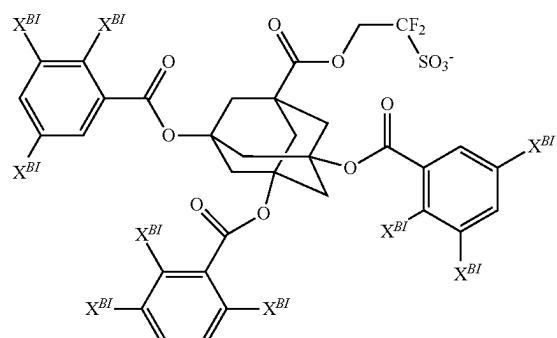
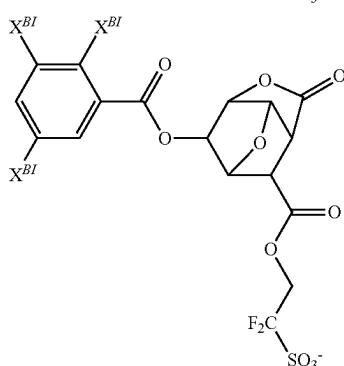
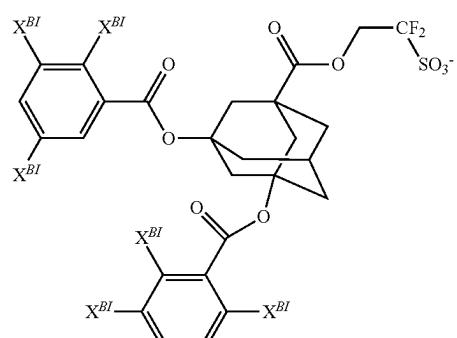
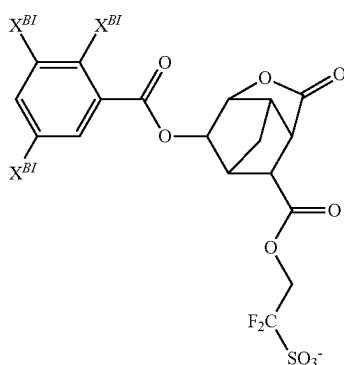
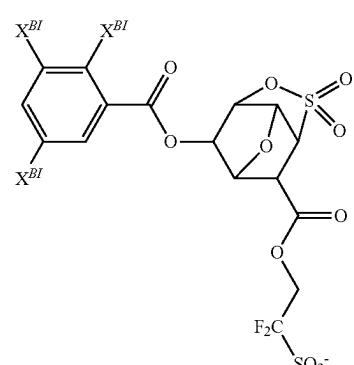
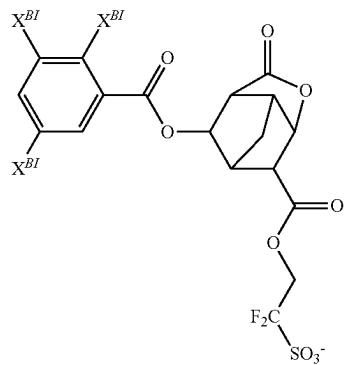
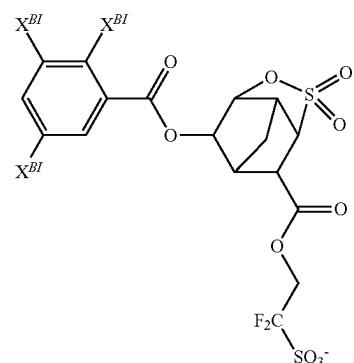
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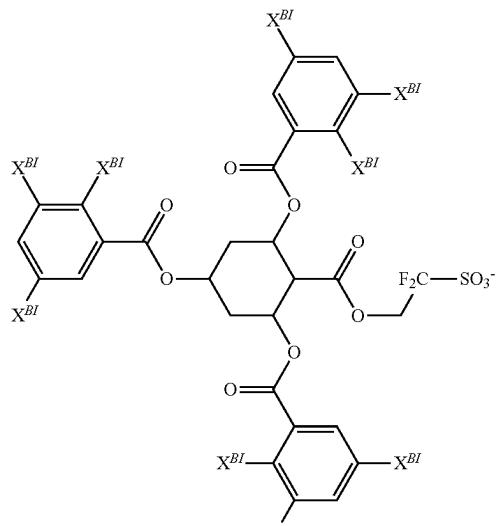
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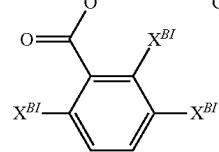
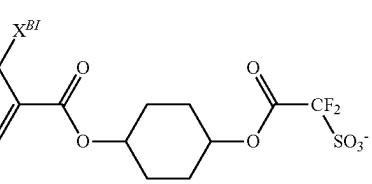
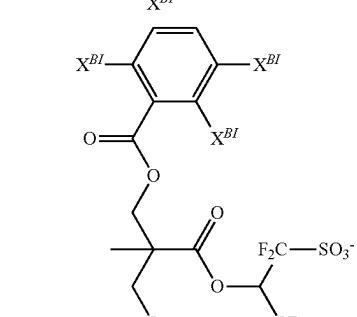
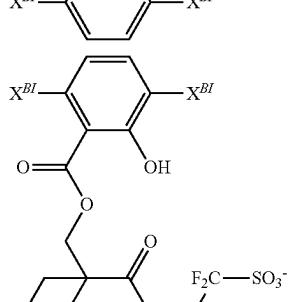
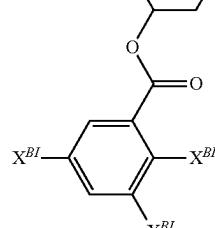
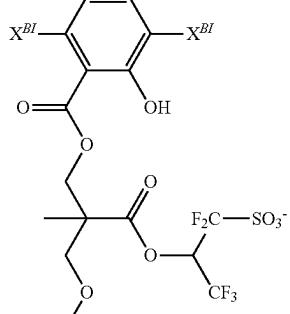
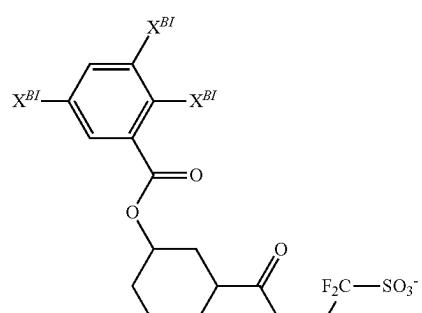
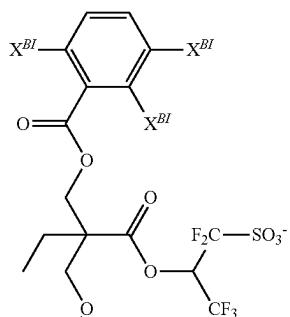
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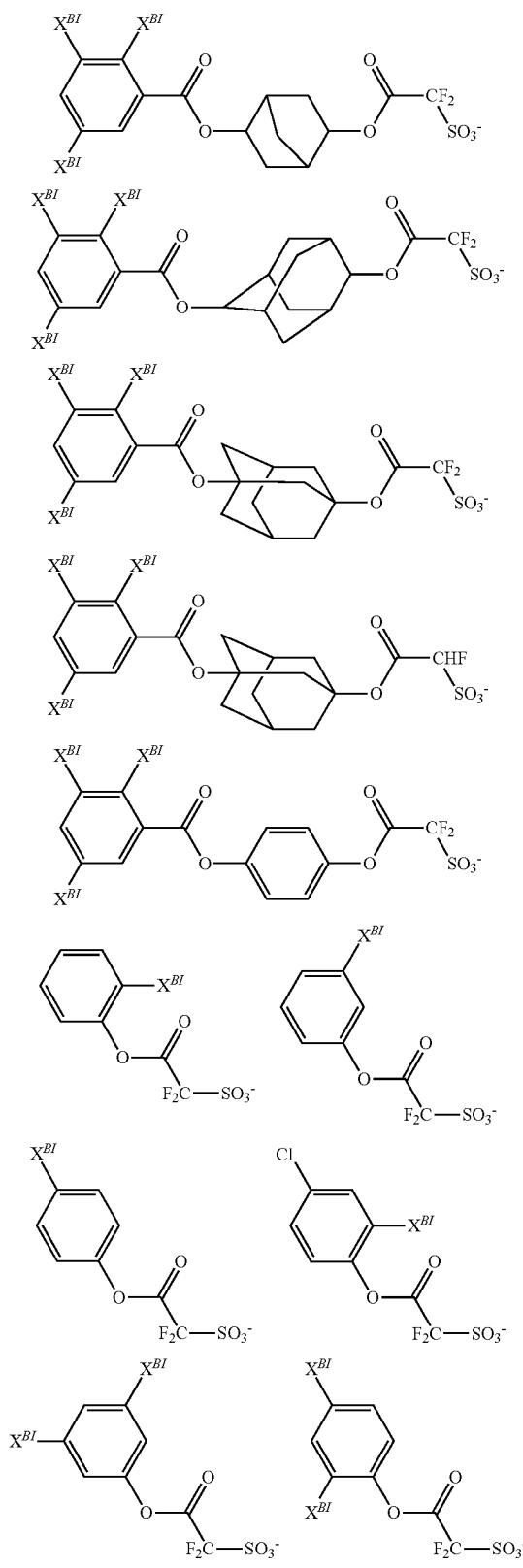
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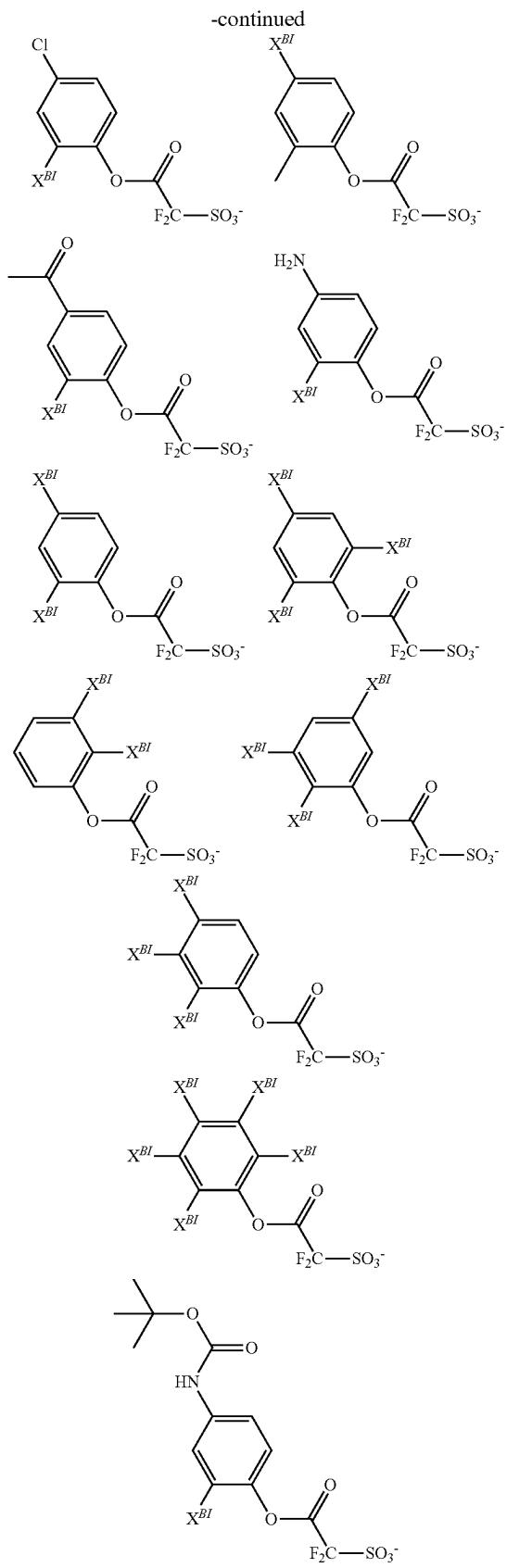
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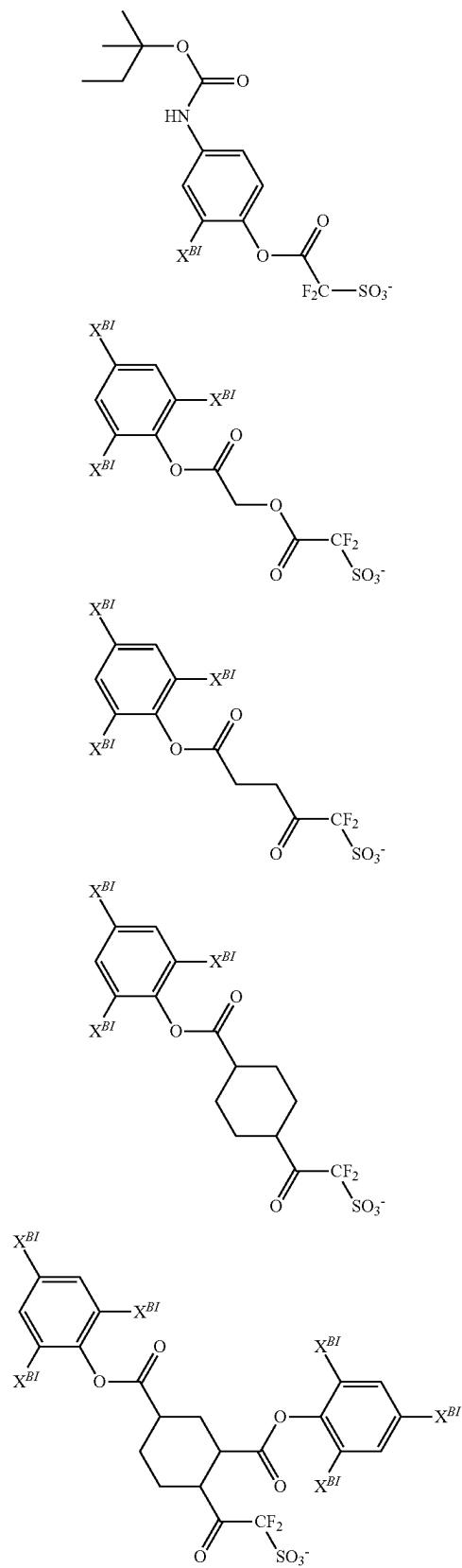
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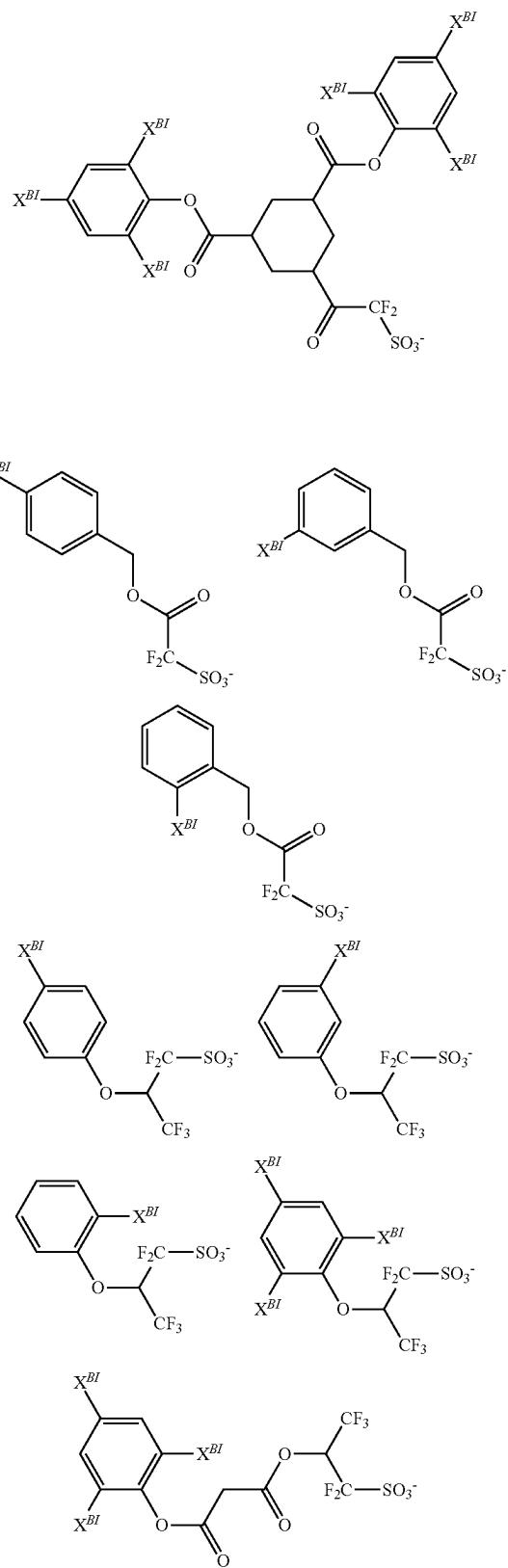
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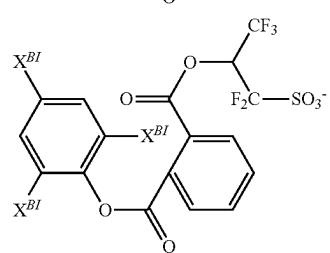
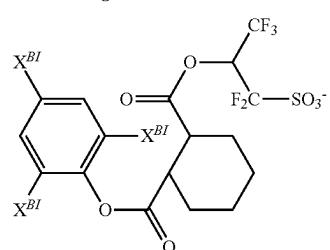
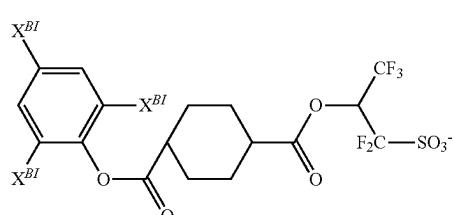
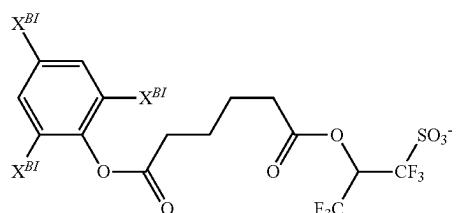
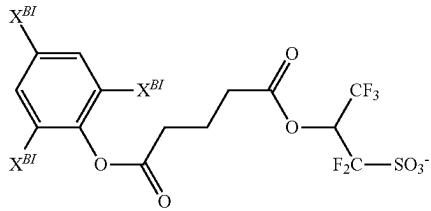
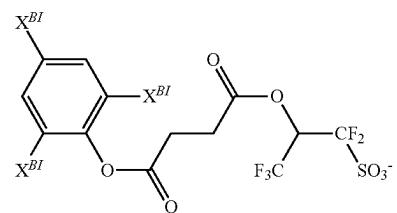
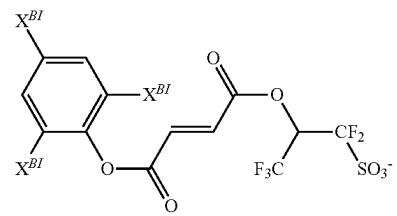
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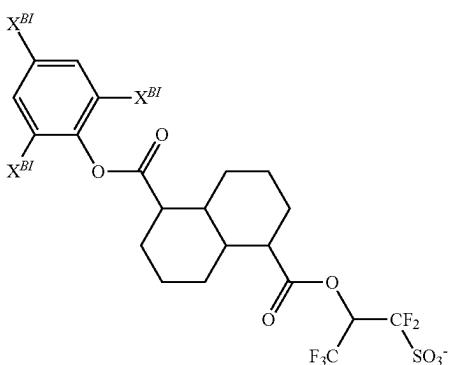
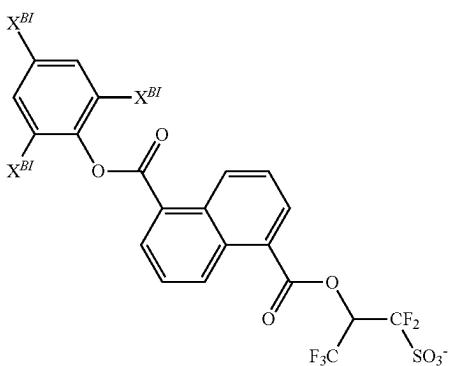
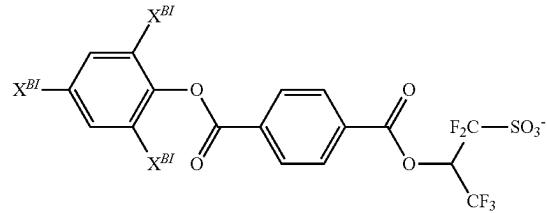
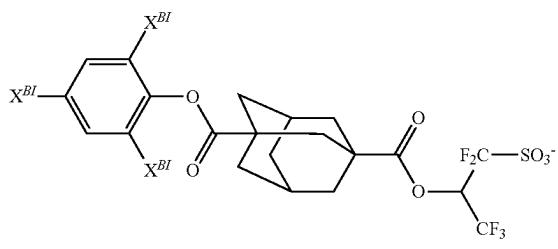
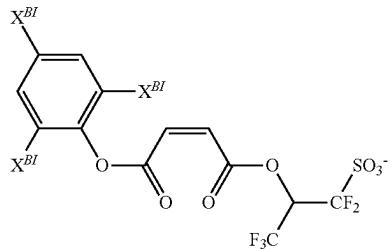
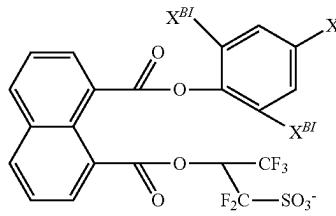
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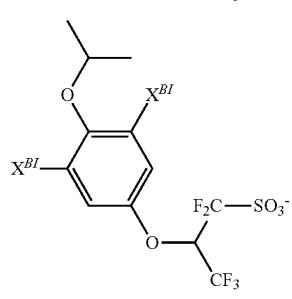
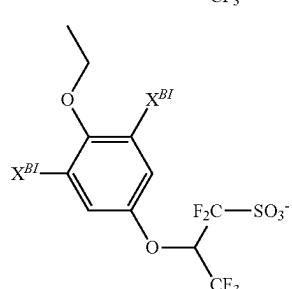
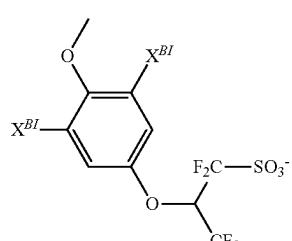
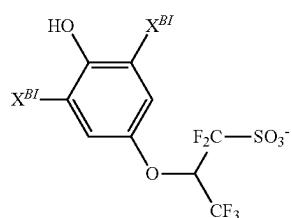
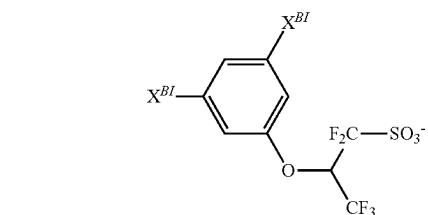
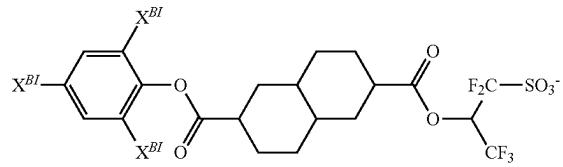
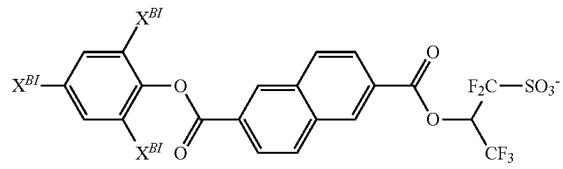
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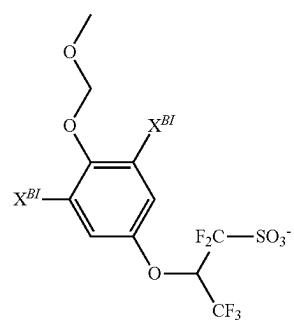
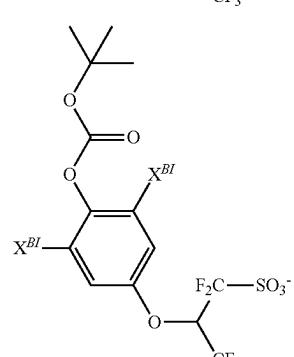
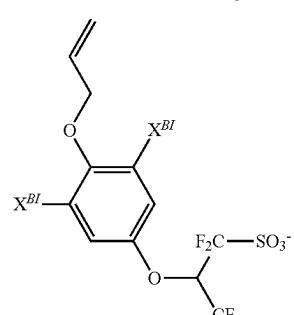
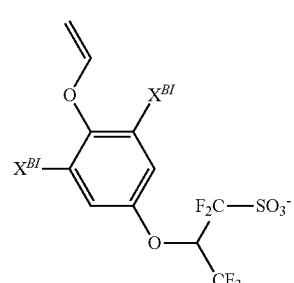
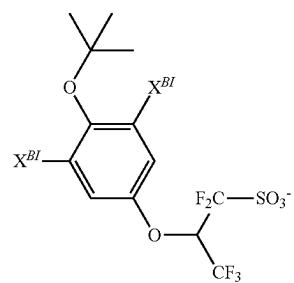
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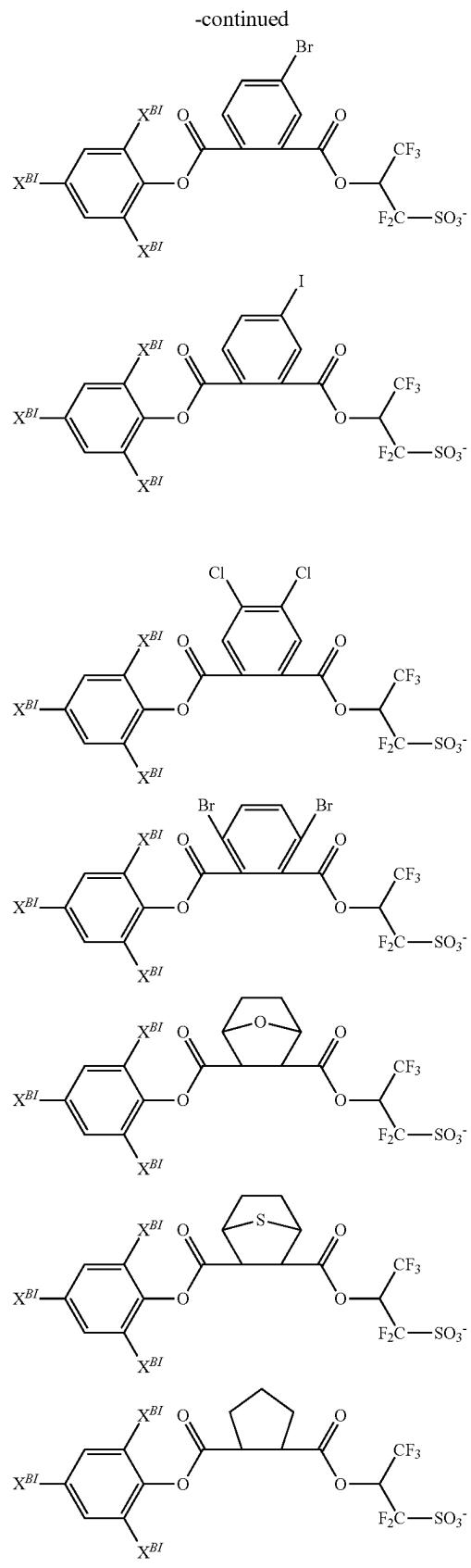
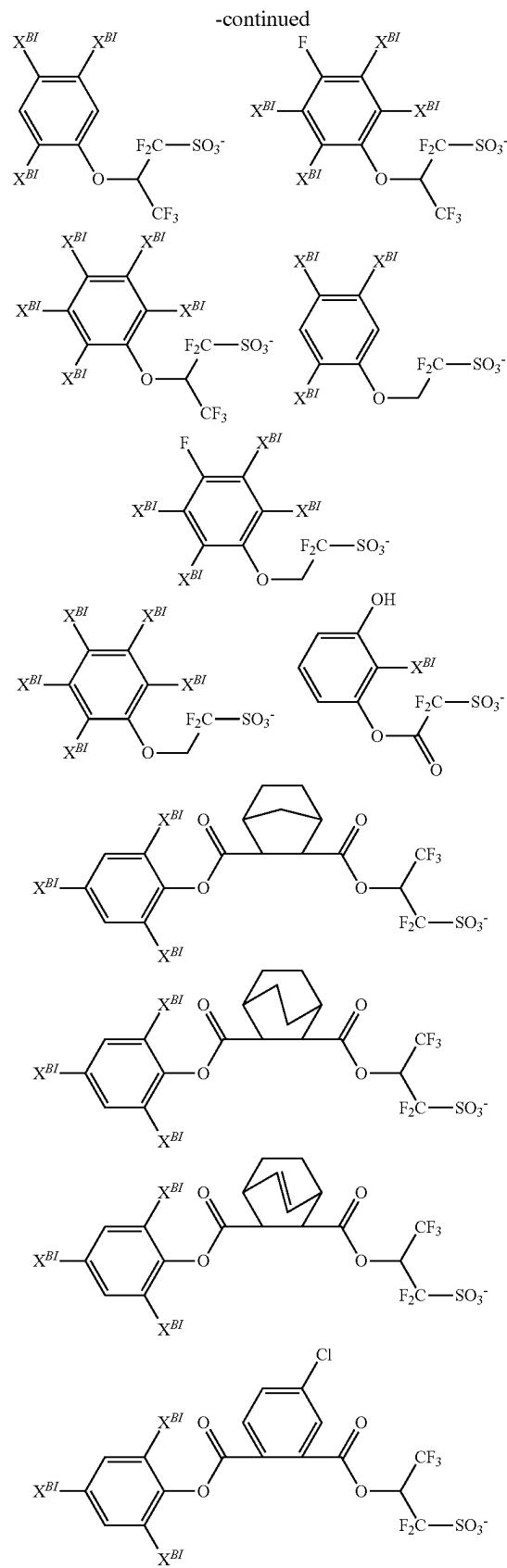


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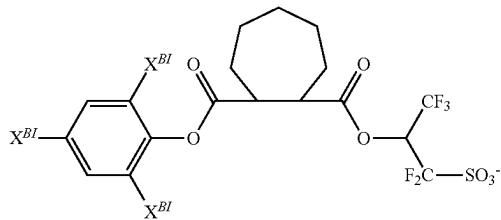


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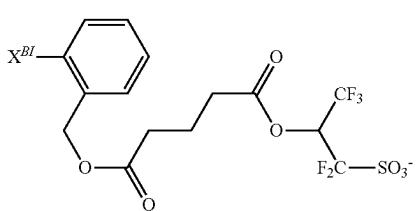
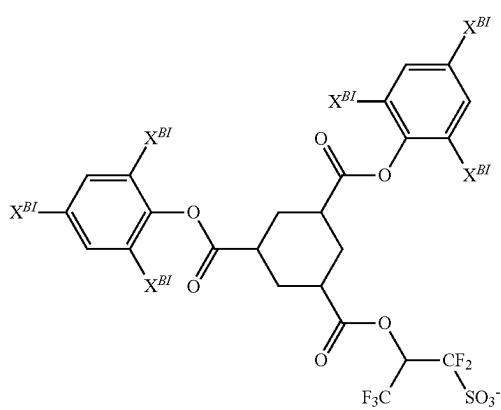
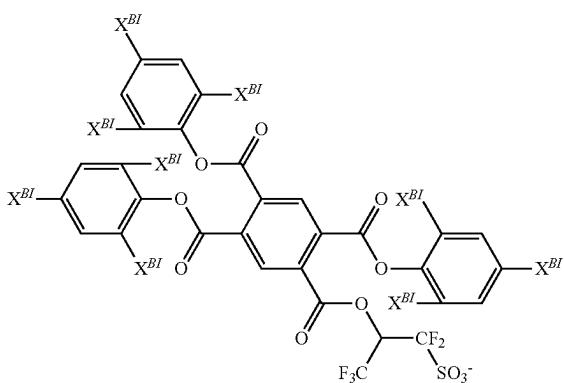
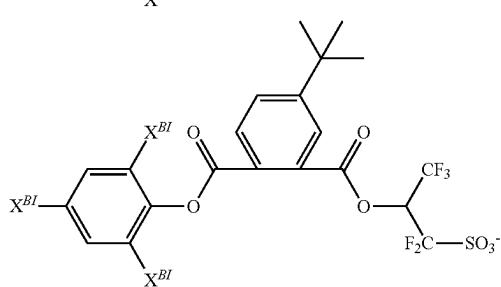
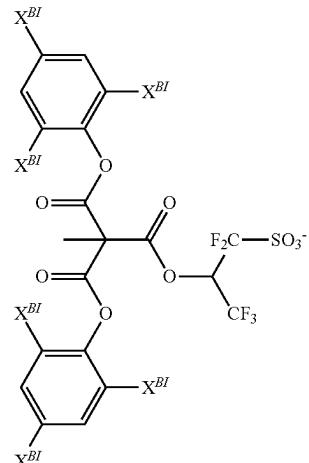
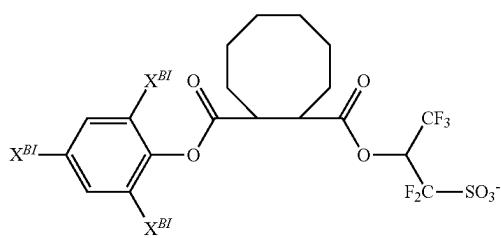
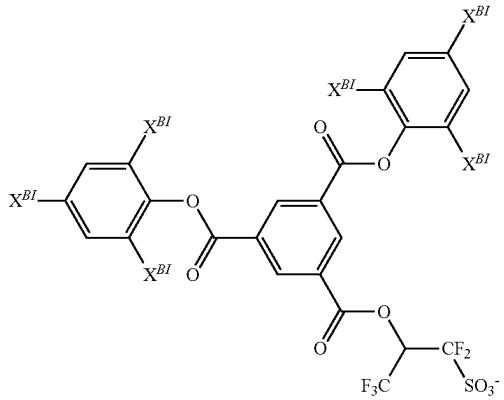




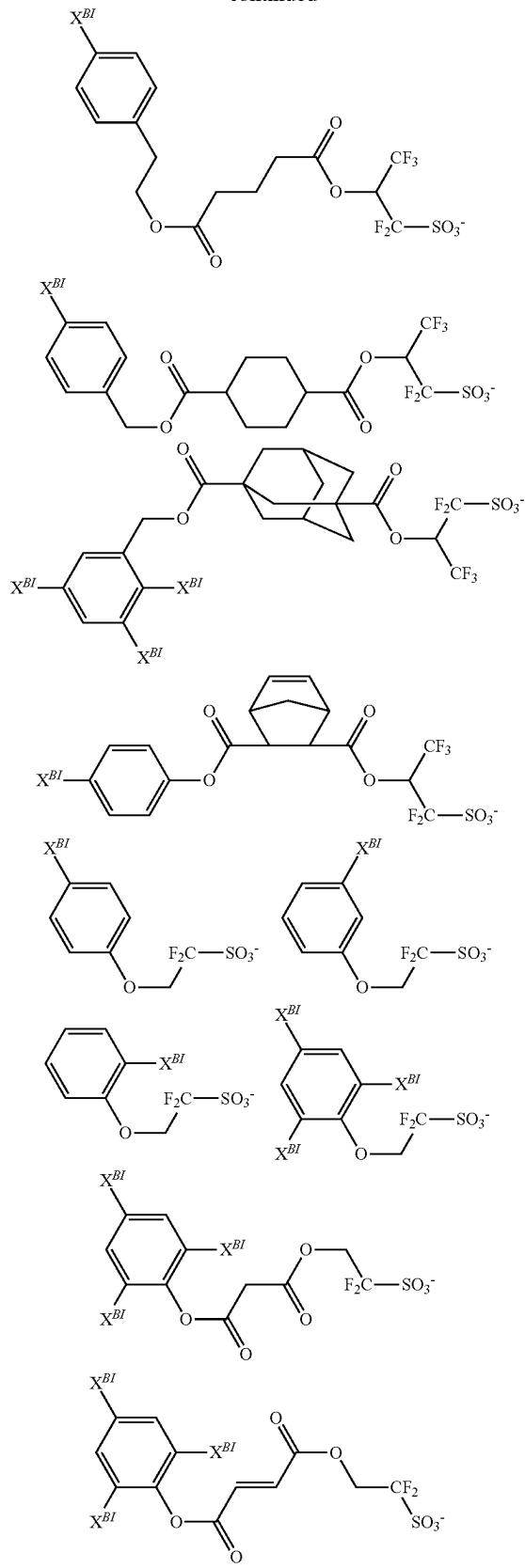
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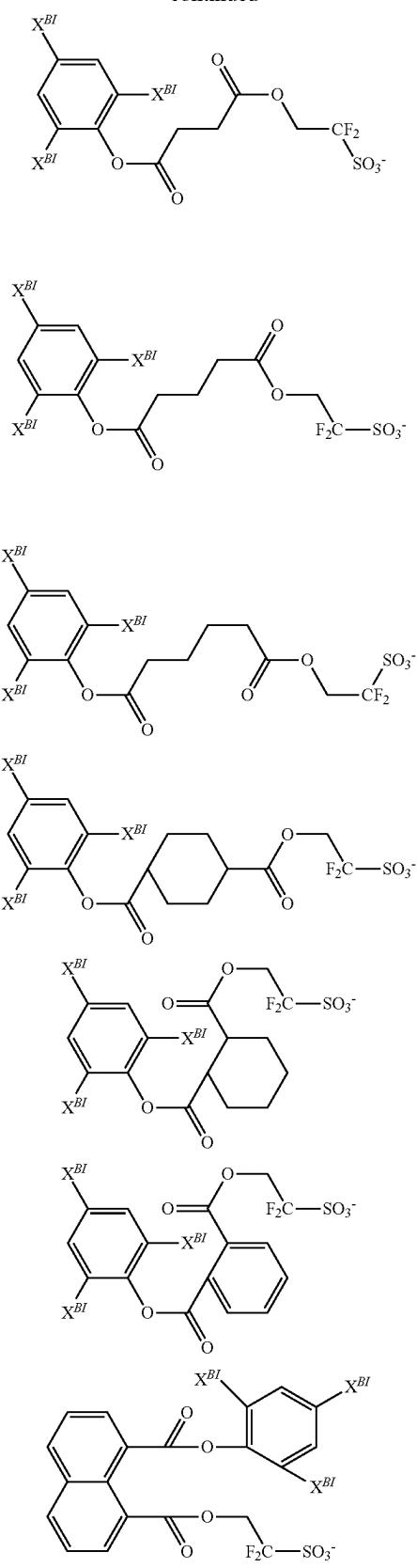
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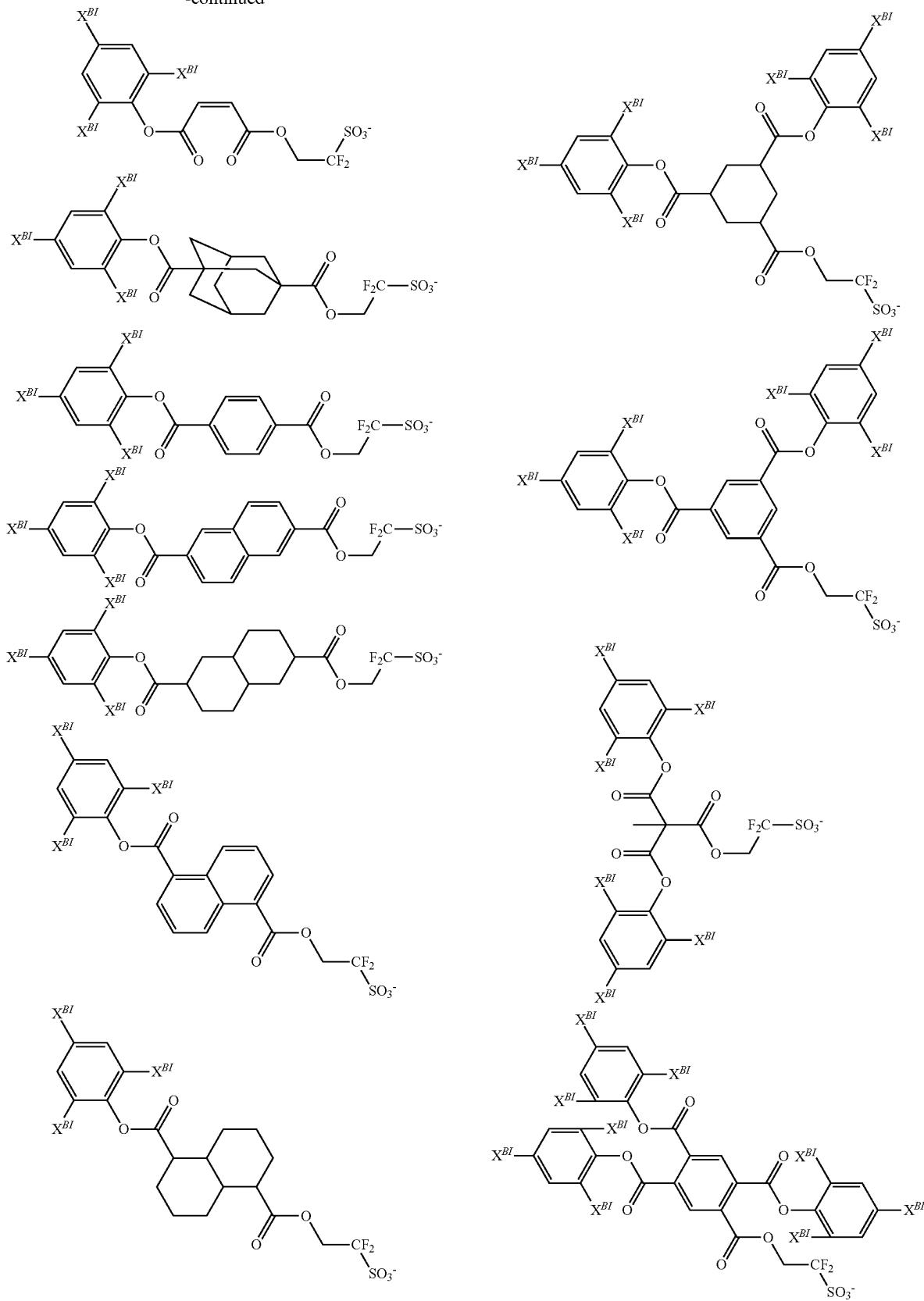
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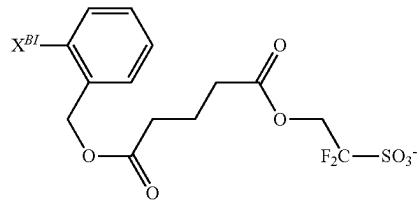
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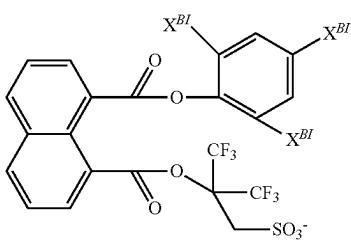
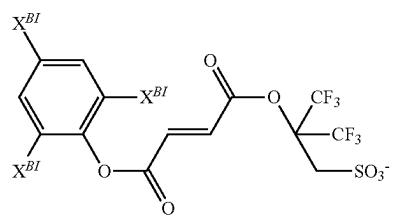
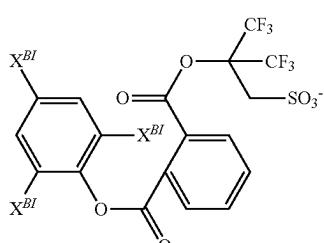
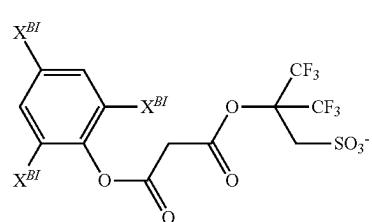
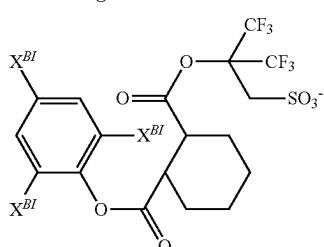
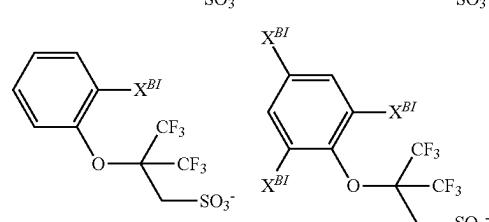
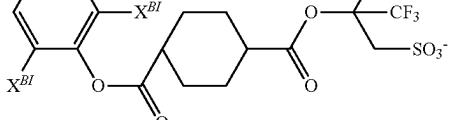
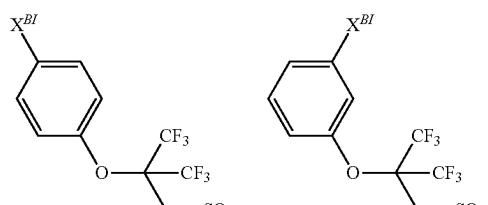
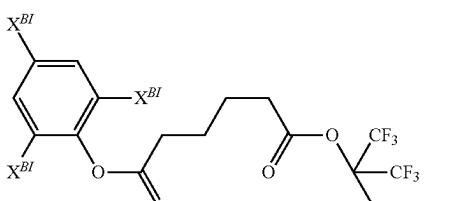
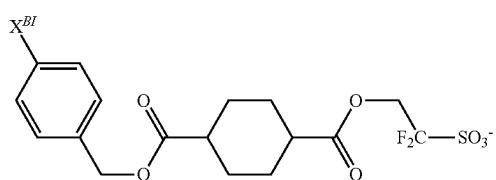
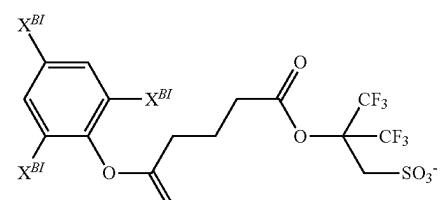
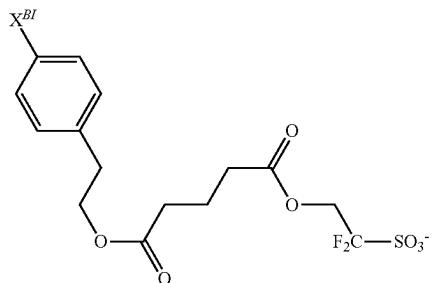
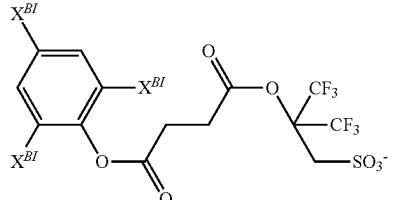
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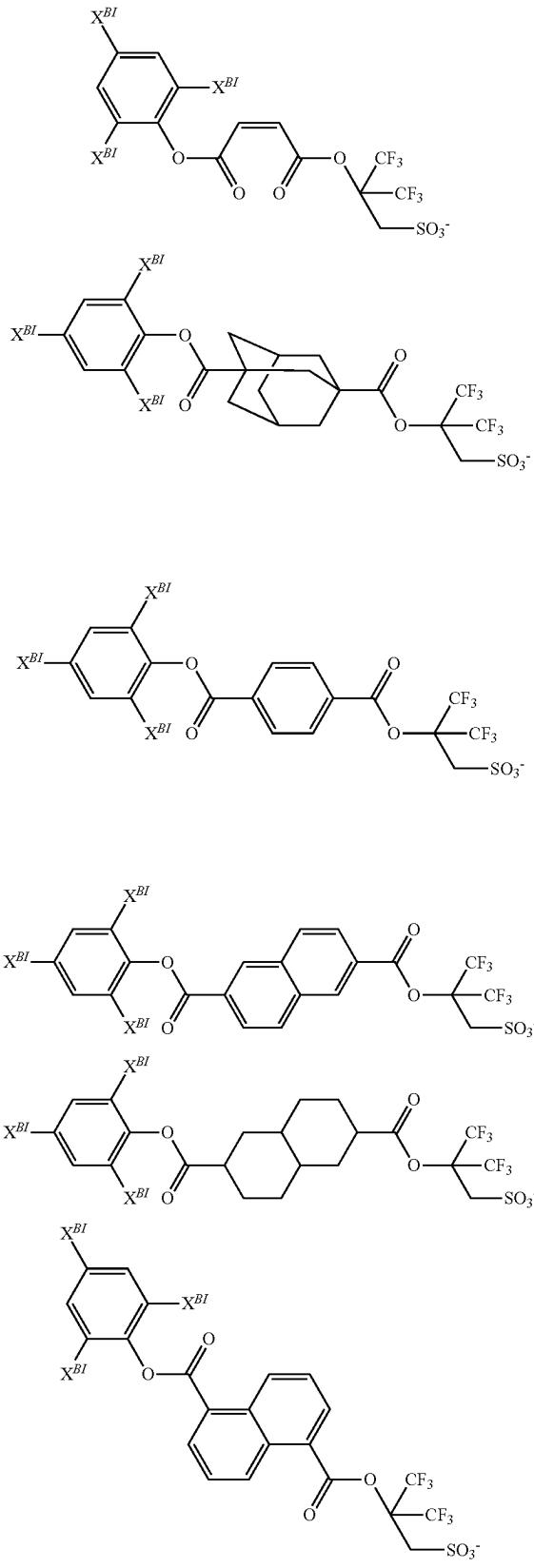
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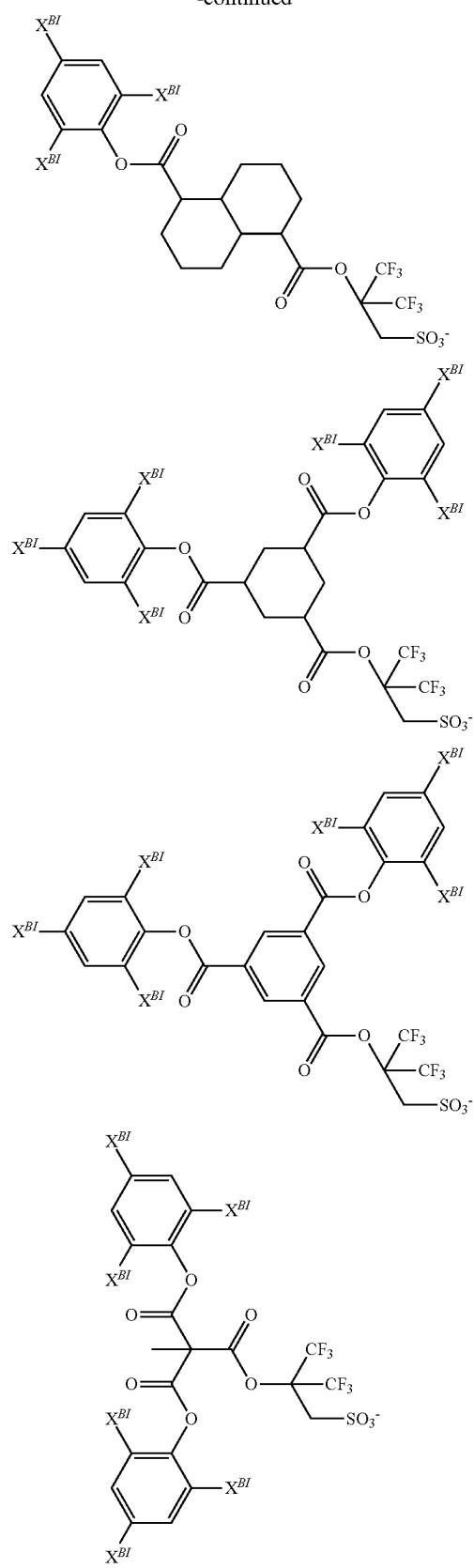
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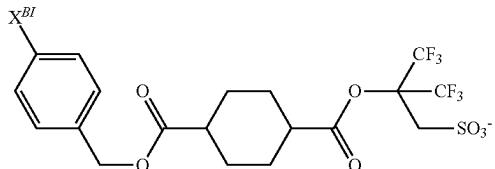
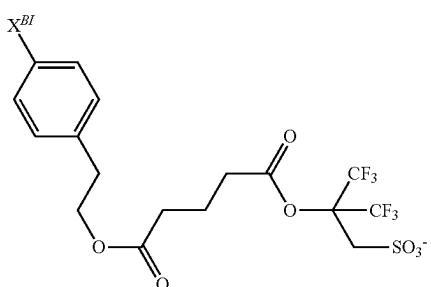
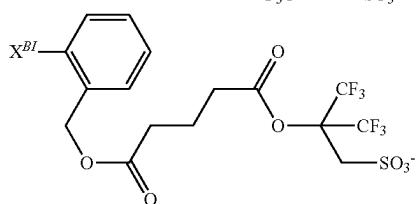
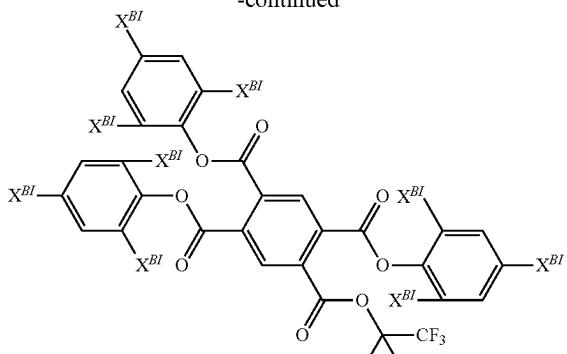
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[0224] Other useful examples of the non-nucleophilic counter ion include fluorobenzenesulfonic acid anions having an iodized aromatic ring bonded thereto as described in JP 6648726, anions having an acid-catalyzed decomposition mechanism as described in WO 2021/200056 and JP-A 2021-070692, anions having a cyclic ether group as described in JP-A 2018-180525 and JP-A 2021-035935, and anions as described in JP-A 2018-092159.

[0225] Further useful examples of the non-nucleophilic counter ion include bulky fluorine-free benzenesulfonic acid anions as described in JP-A 2006-276759, JP-A 2015-117200, JP-A 2016-065016, and JP-A 2019-202974; fluorine-free benzenesulfonic acid or alkylsulfonic acid anions having an iodized aromatic group bonded thereto as described in JP 6645464.

[0226] Also useful are bisulfonic acid anions as described in JP-A 2015-206932, sulfonamide or sulfonimide anions having sulfonic acid side and different side as described in WO 2020/158366, and anions having a sulfonic acid side and a carboxylic acid side as described in JP-A 2015-024989.

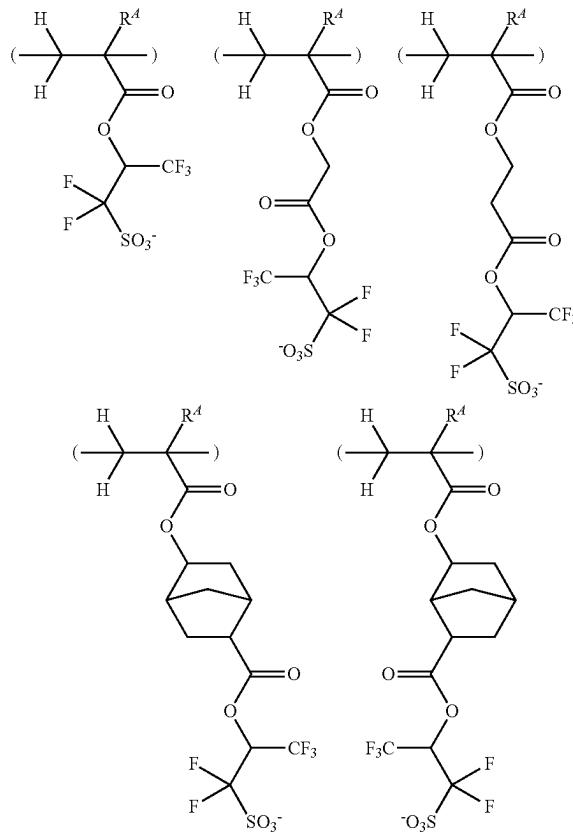
[0227] In formulae (c2) and (c3), L¹ is a single bond, ether bond, ester bond, carbonyl, sulfonate ester bond, carbonate bond or carbamate bond. From the aspect of synthesis, an ether bond, ester bond or carbonyl group is preferred, with the ester bond or carbonyl being more preferred.

[0228] In formula (c2), Rf¹ and Rf² are each independently fluorine or a C₁-C₆ fluorinated saturated hydrocarbyl group. It is preferred that both Rf¹ and Rf² be fluorine because the generated acid has a higher acid strength. Rf³ and Rf⁴ are each independently hydrogen, fluorine or a C₁-C₆ fluorinated saturated hydrocarbyl group. It is preferred for solvent solubility that at least one of Rf³ and Rf⁴ be trifluoromethyl.

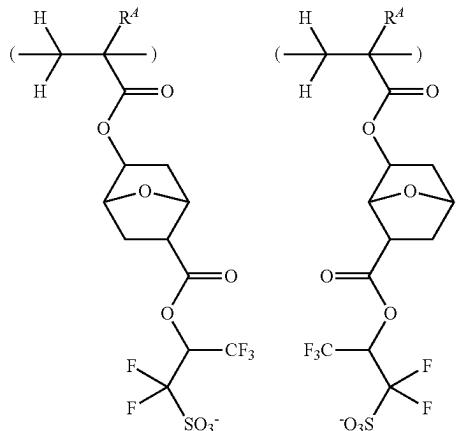
[0229] In formula (c3), Rf⁵ and Rf⁶ are each independently hydrogen, fluorine or a C₁-C₆ fluorinated saturated hydrocarbyl group. It is excluded that all Rf⁵ and Rf⁶ are hydrogen at the same time. It is preferred for solvent solubility that at least one of Rf⁵ and Rf⁶ be trifluoromethyl.

[0230] In formulae (c2) and (c3), d is 0, 1, 2 or 3, preferably 1.

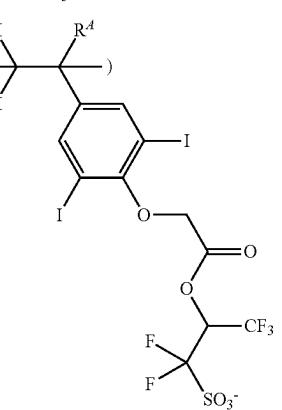
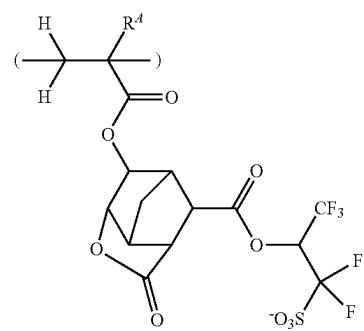
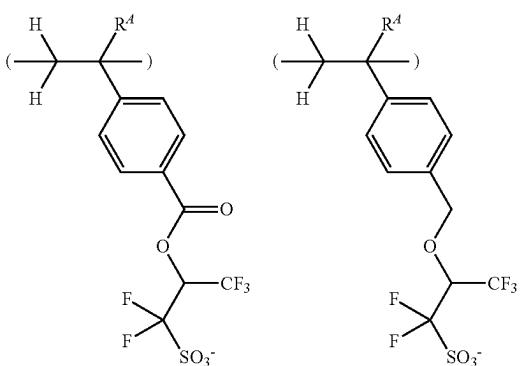
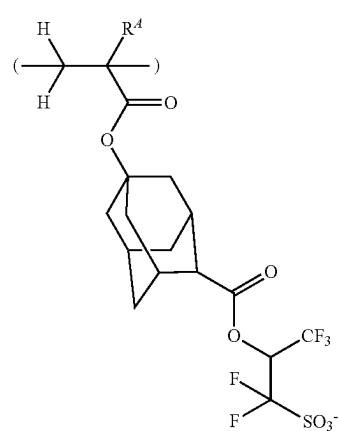
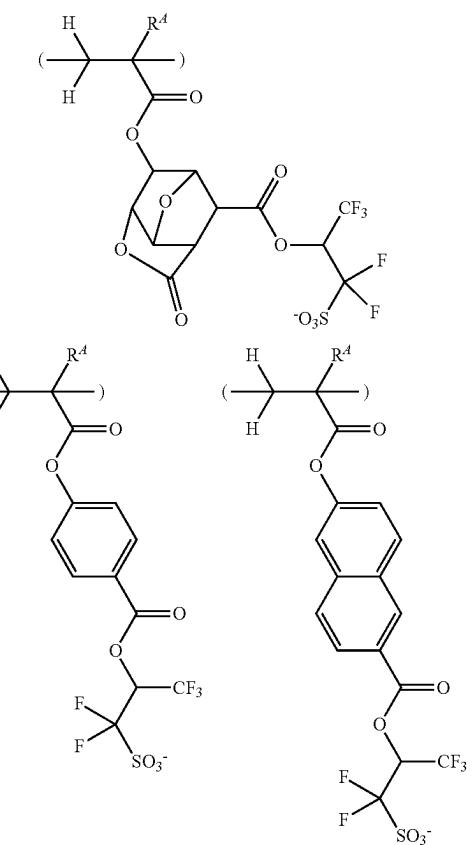
[0231] Examples of the anion in repeat unit (c2) are shown below, but not limited thereto. R⁴ is as defined above.



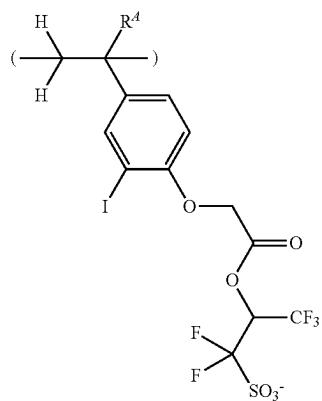
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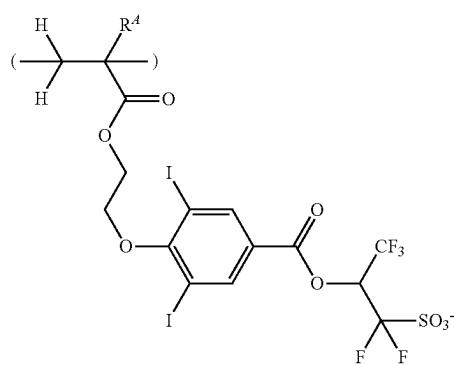
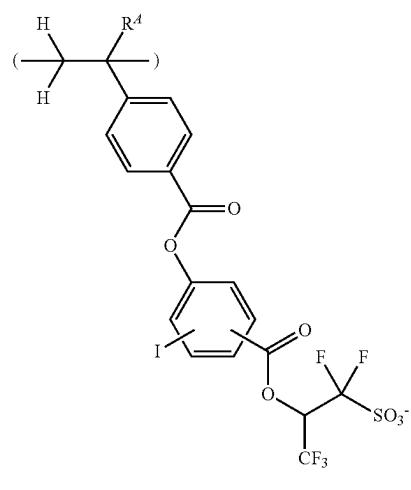
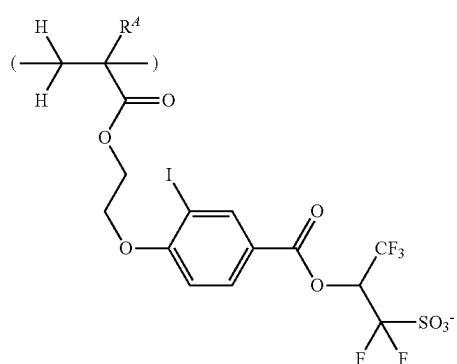
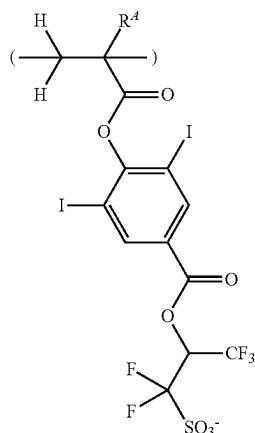
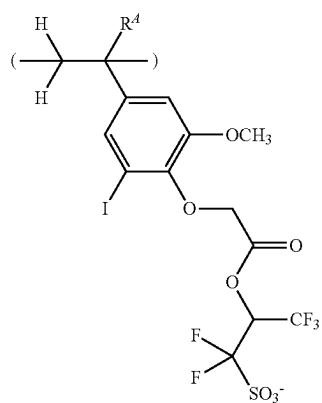
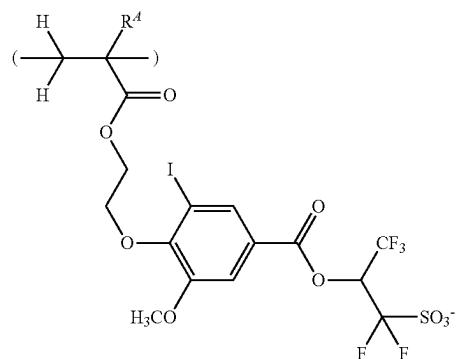
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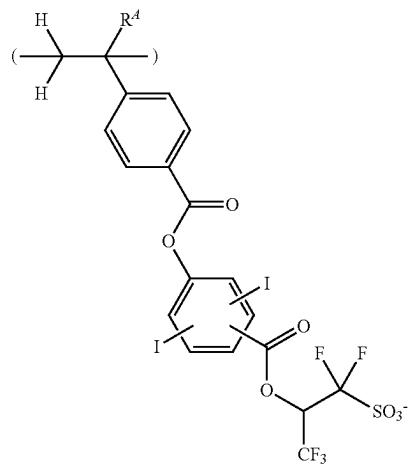
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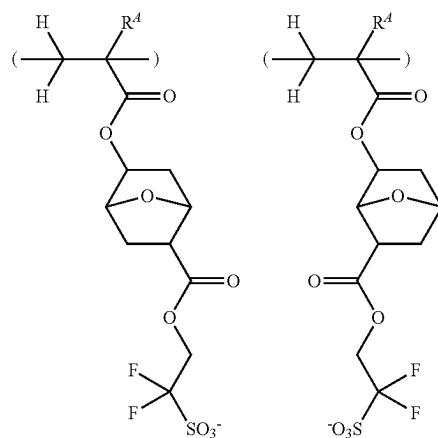
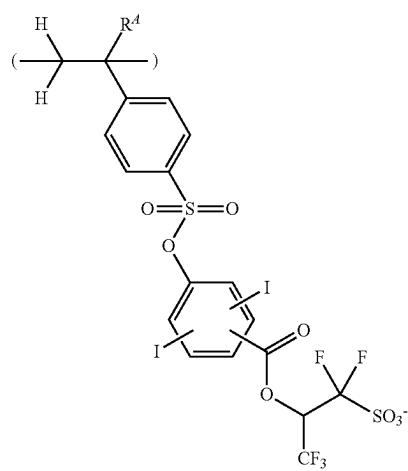
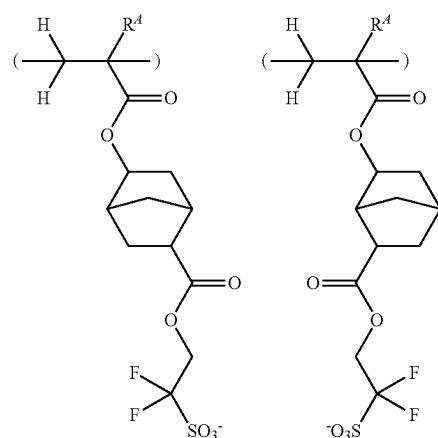
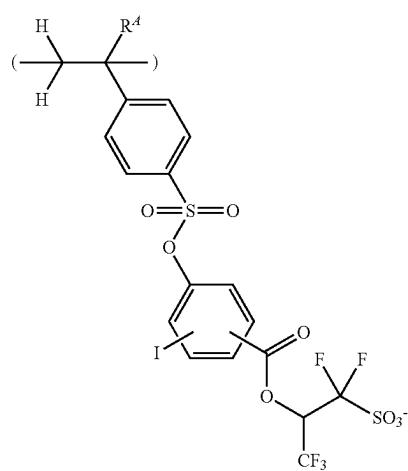
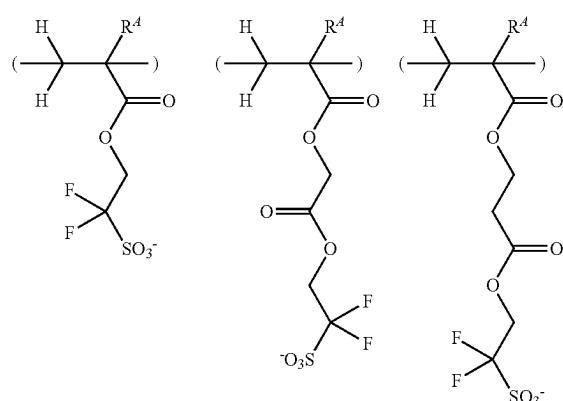
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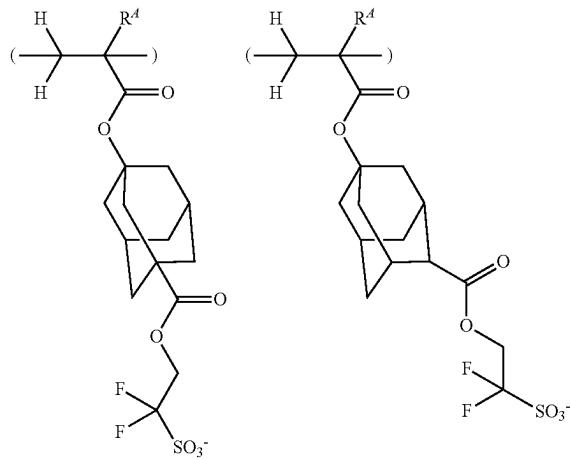
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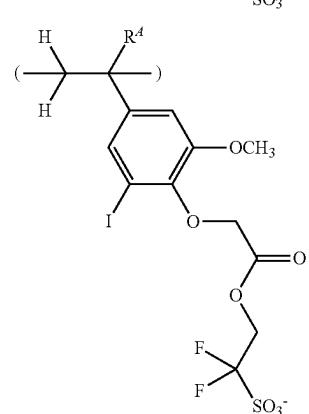
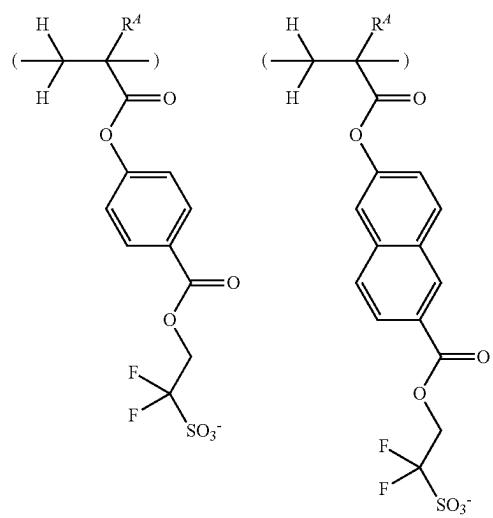
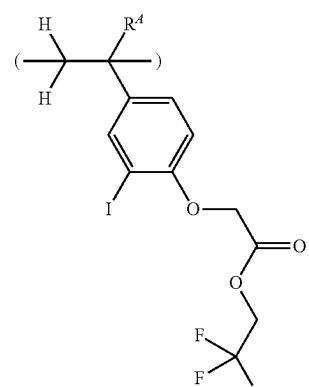
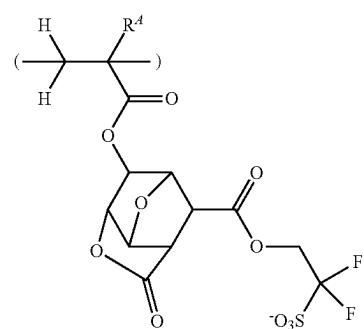
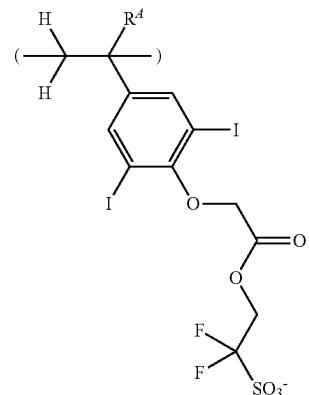
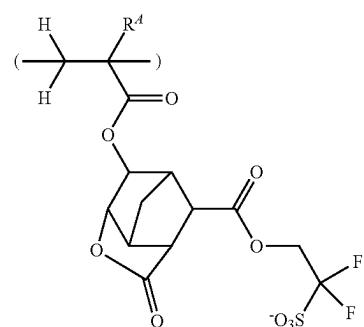
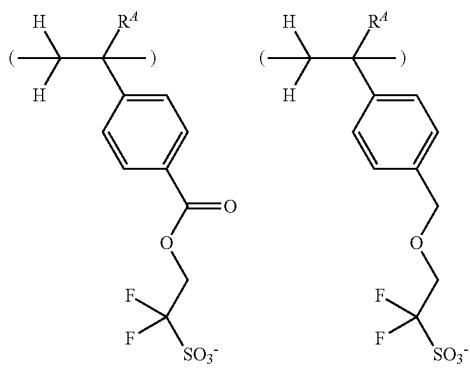
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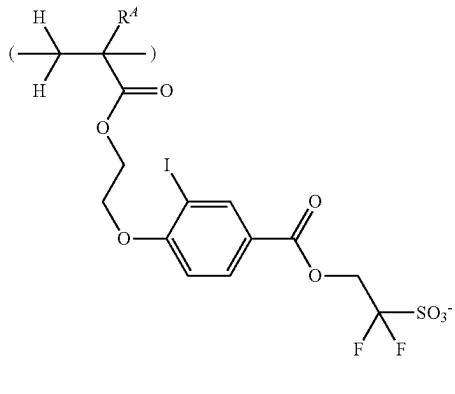
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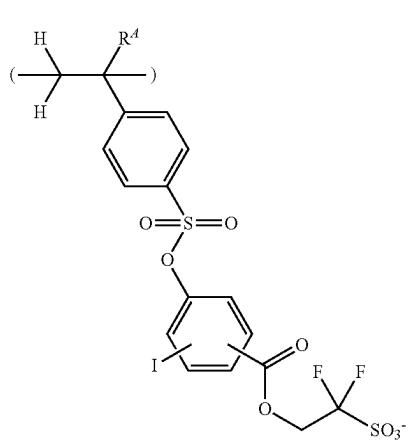
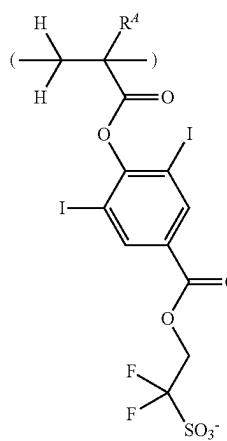
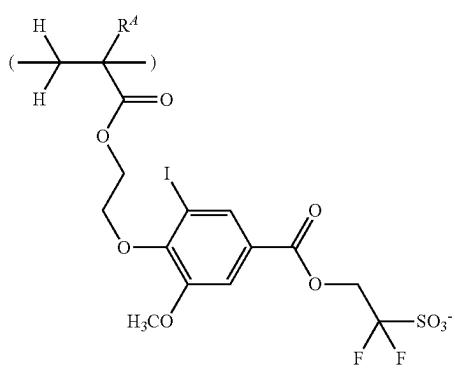
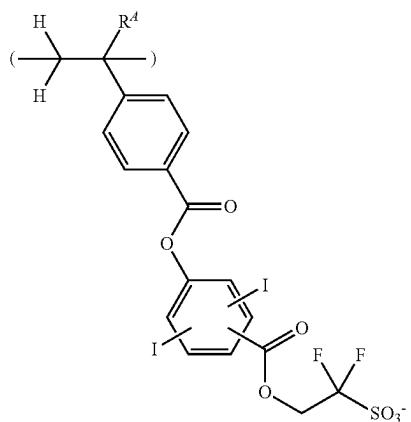
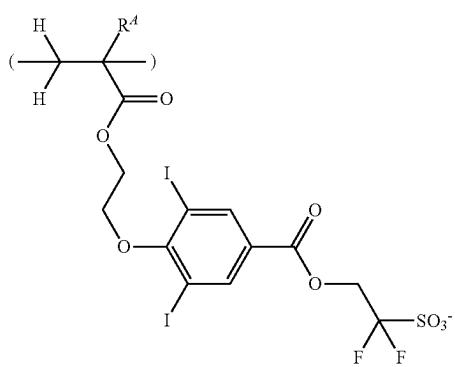
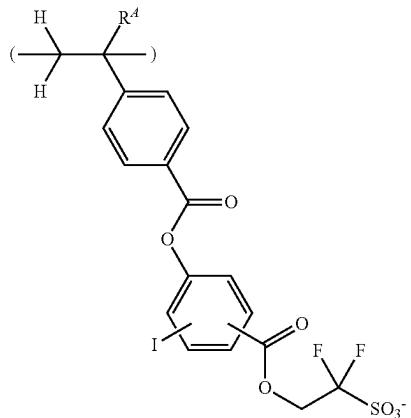
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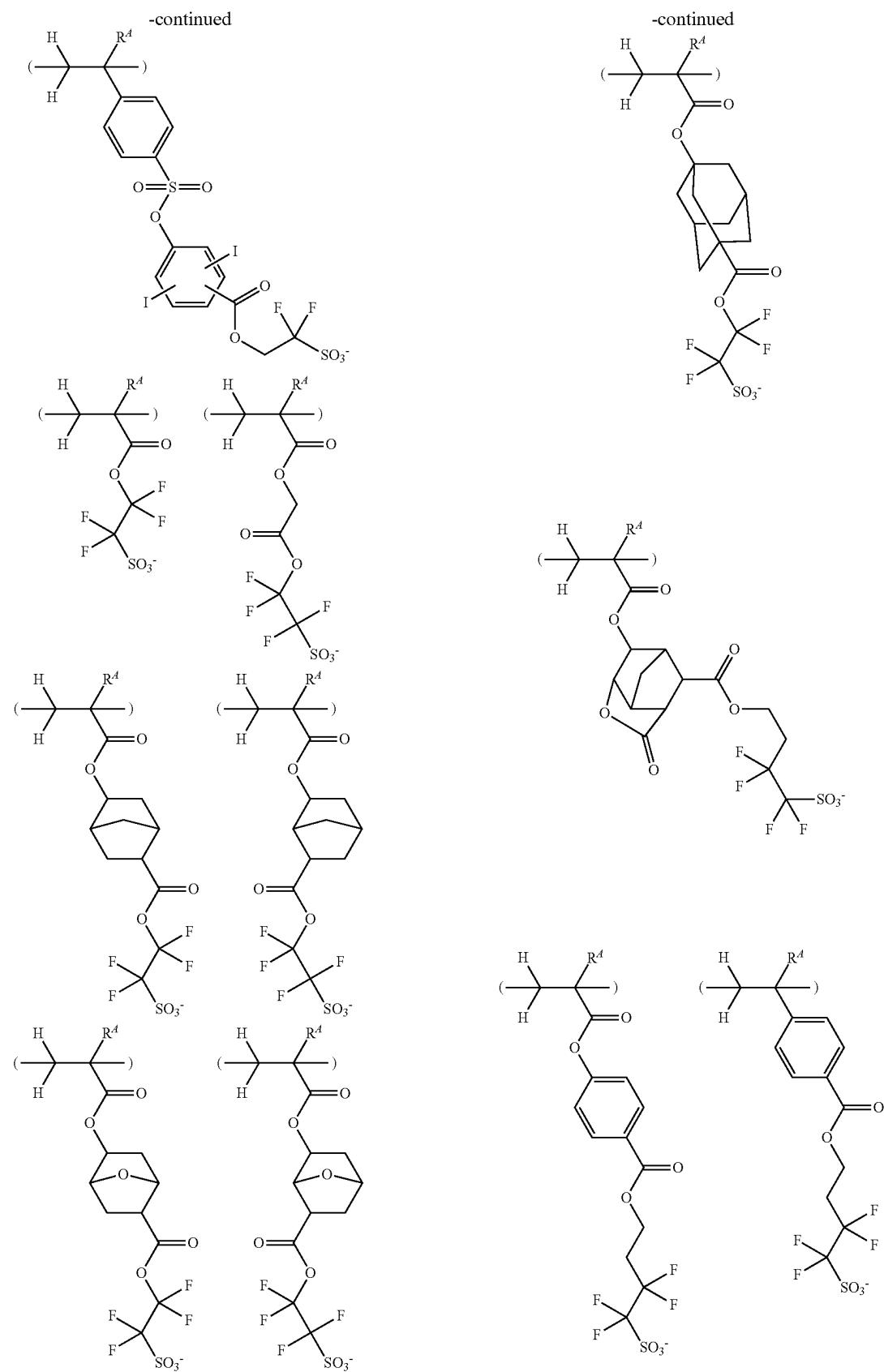


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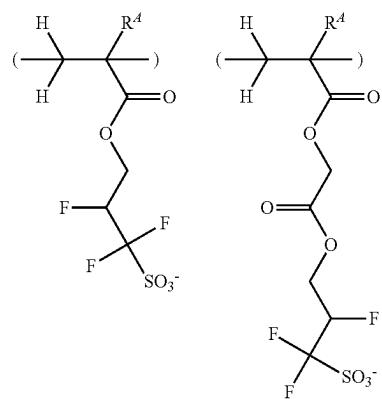


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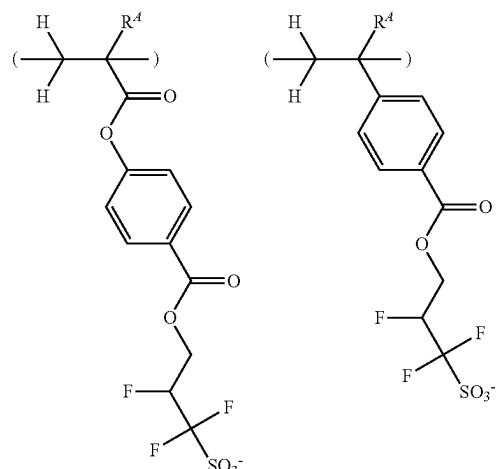
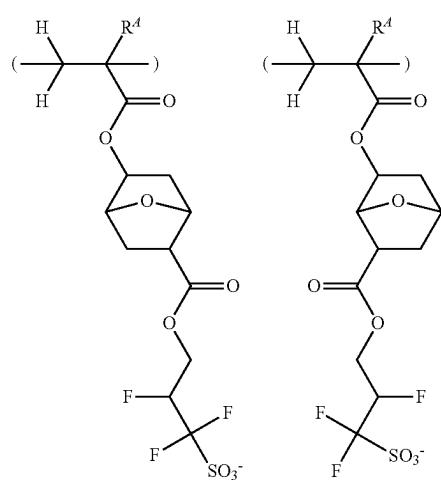
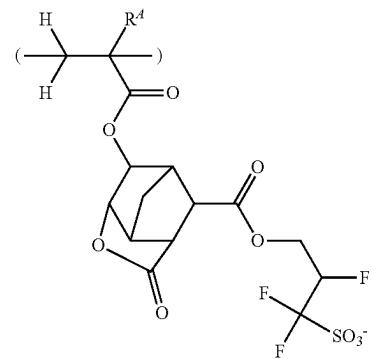
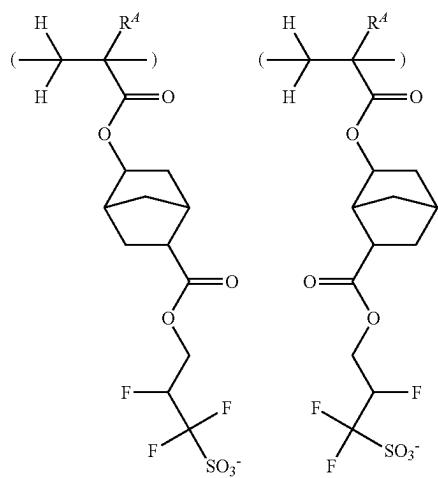
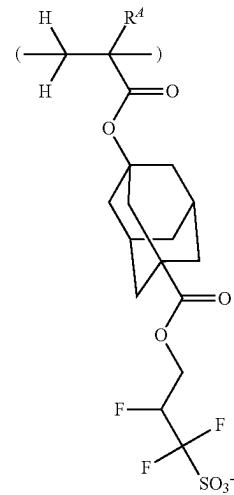




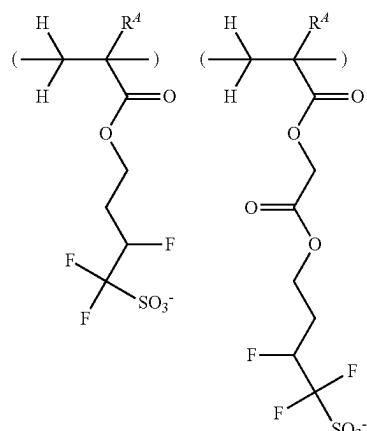
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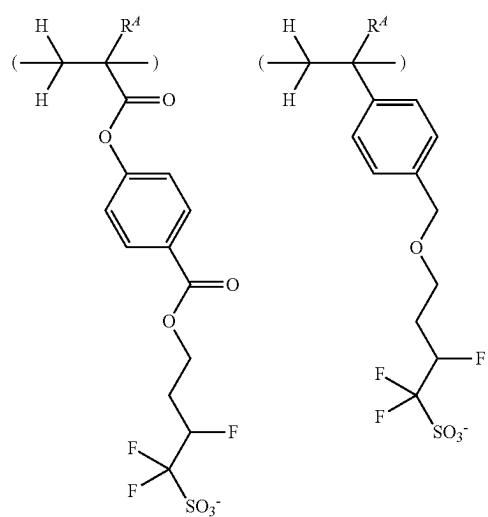
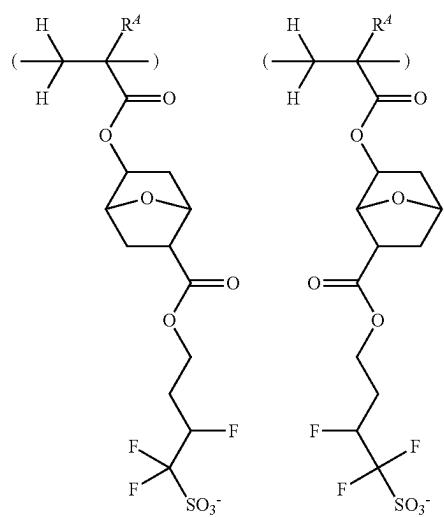
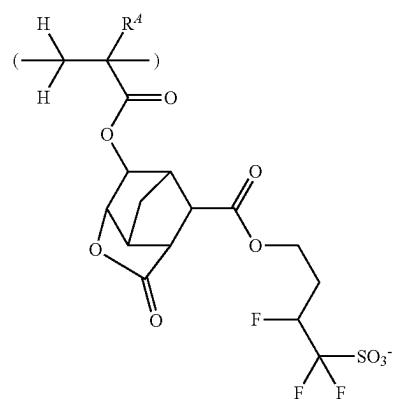
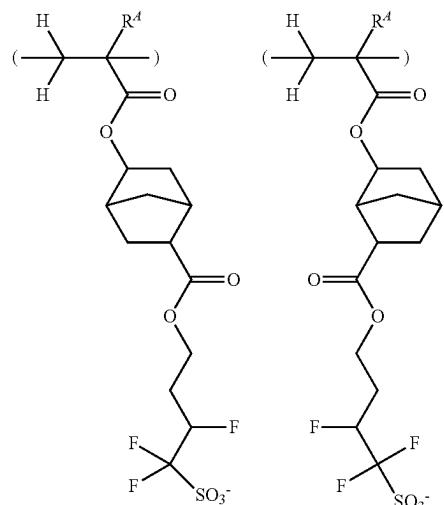
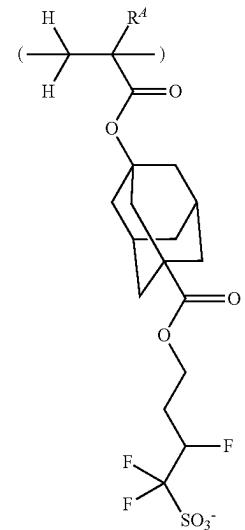
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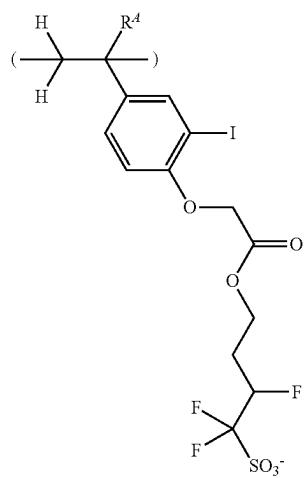
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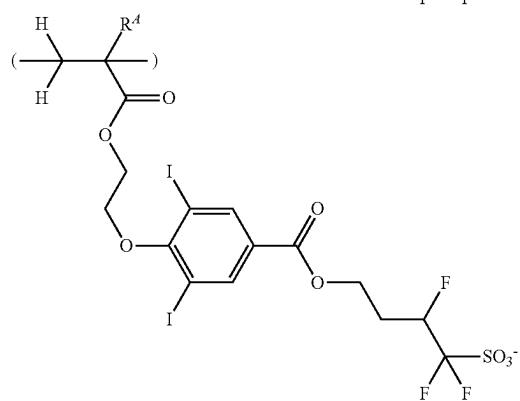
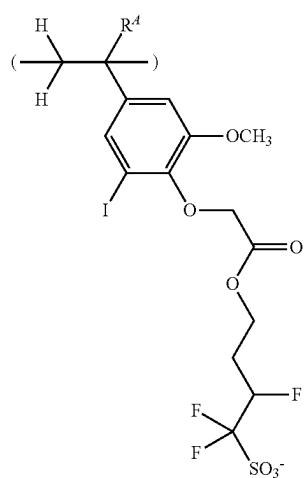
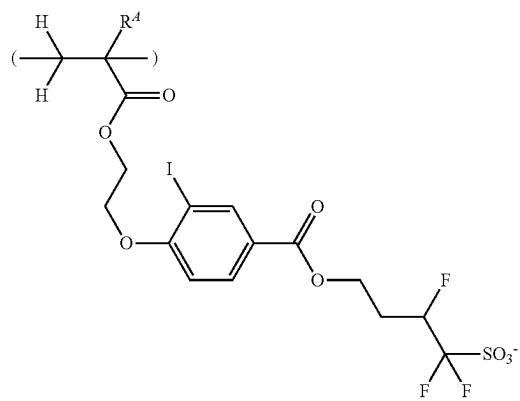
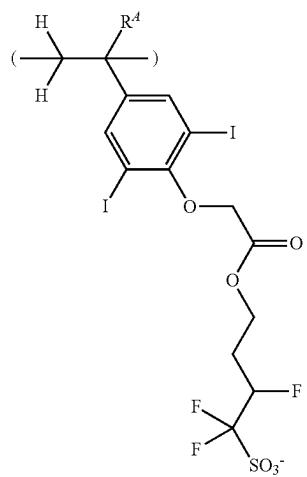
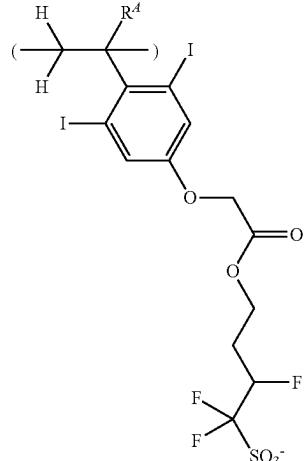
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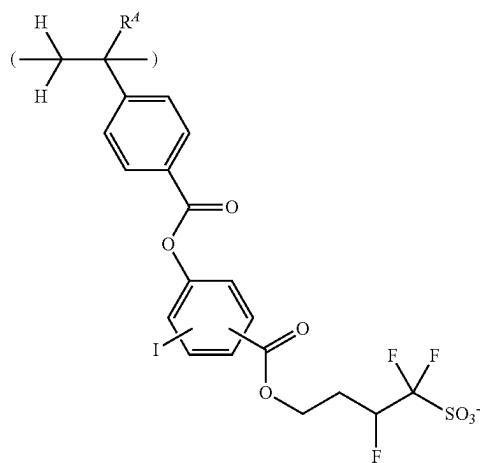
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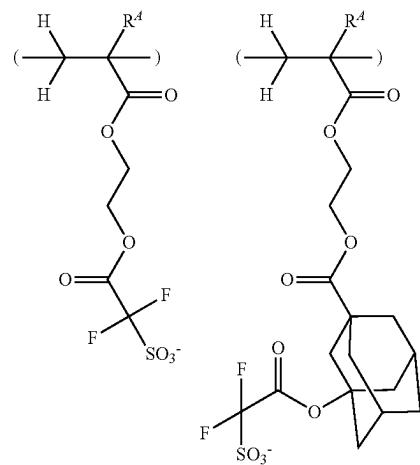
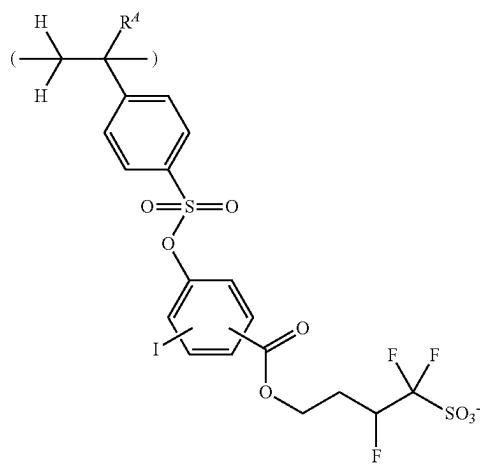
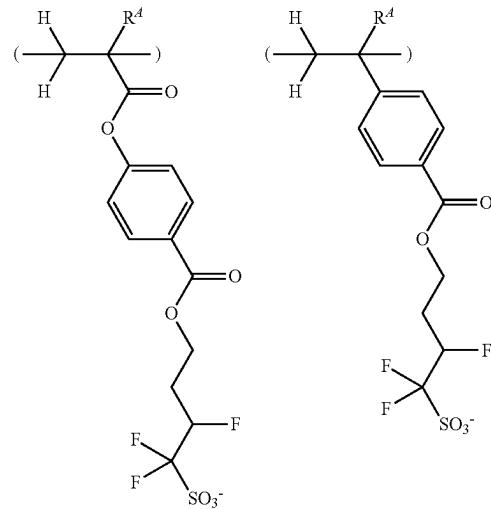
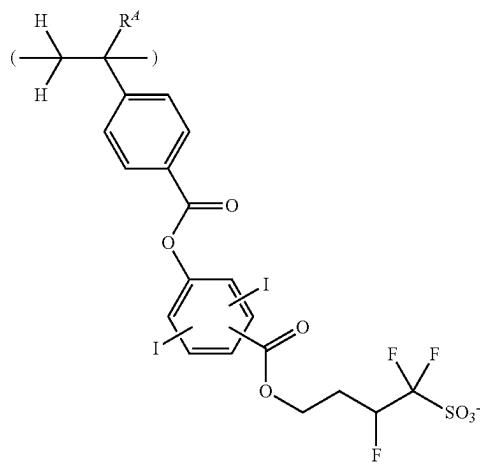
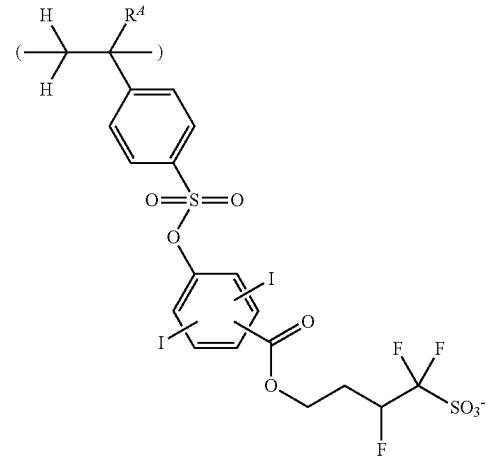
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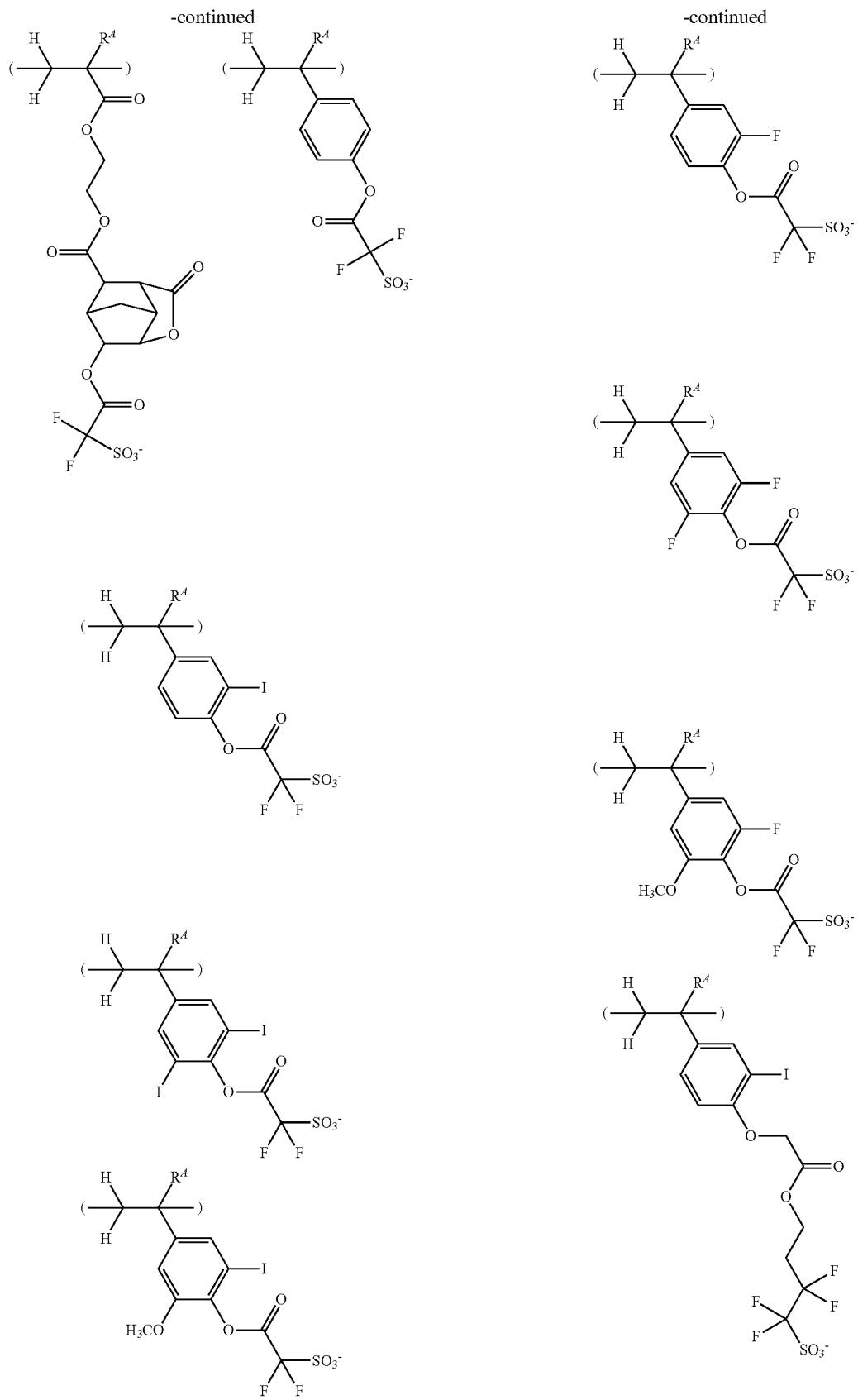


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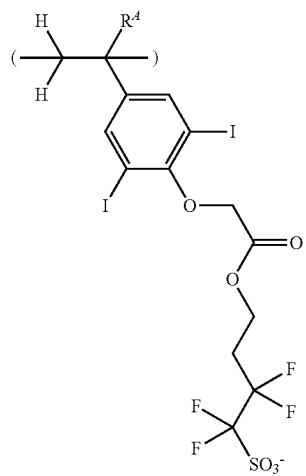


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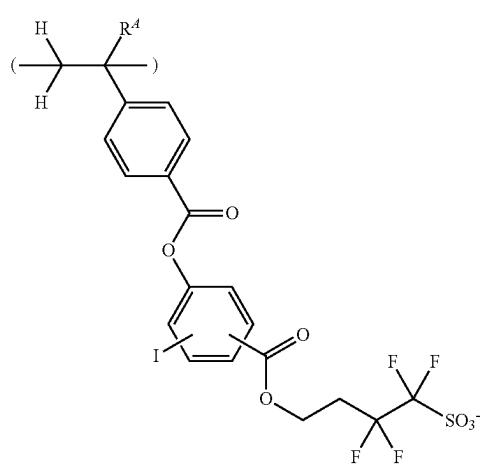
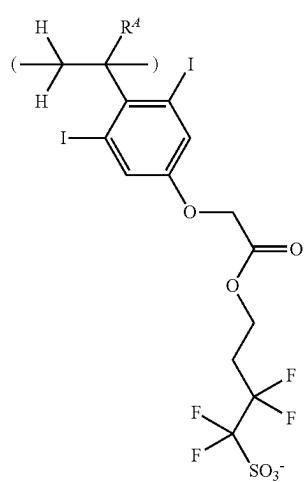
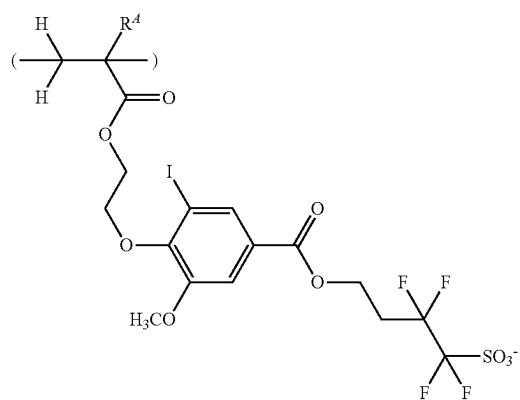
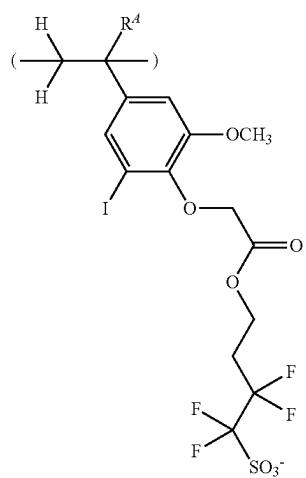
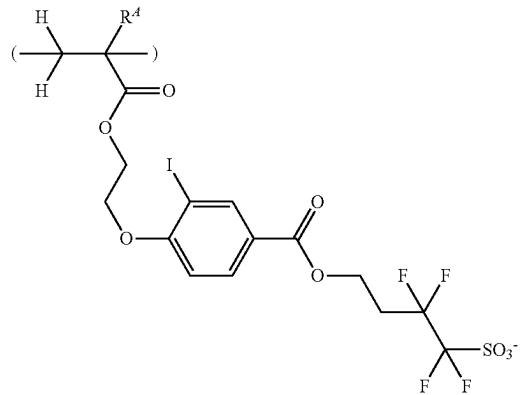




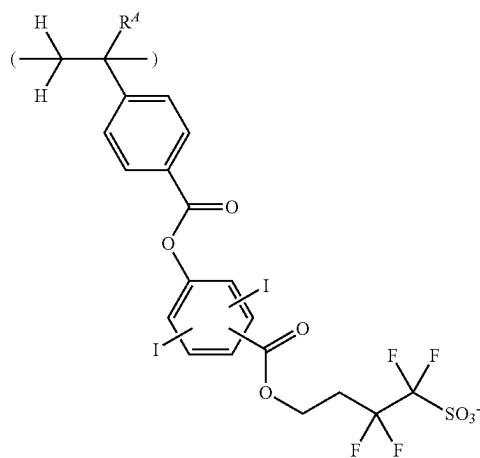
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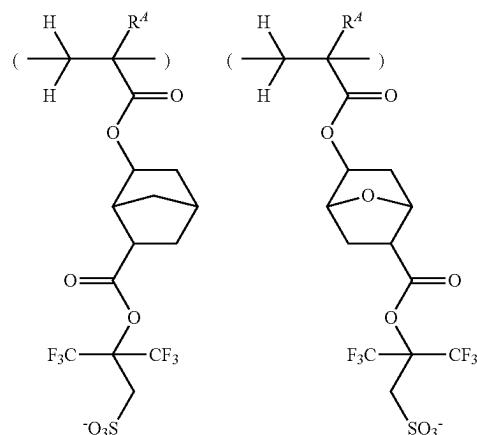
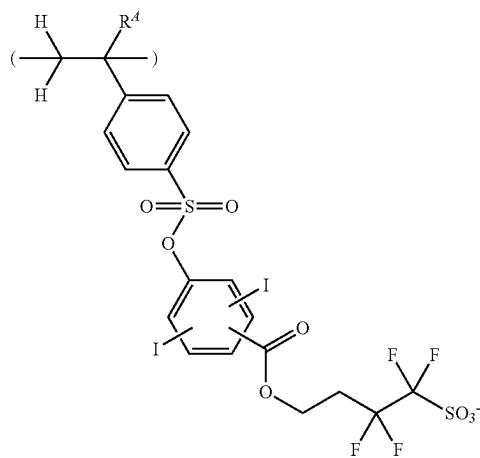
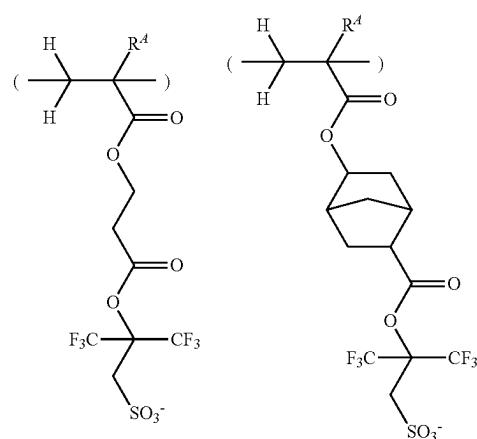
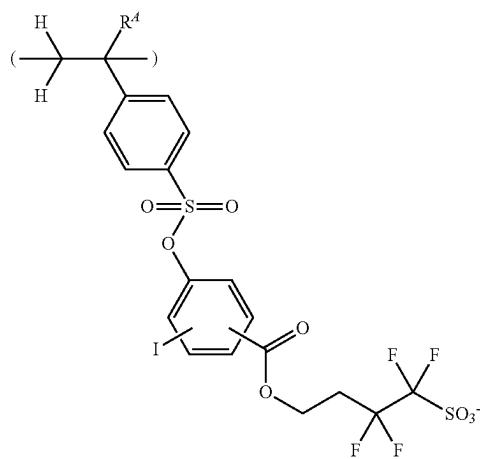
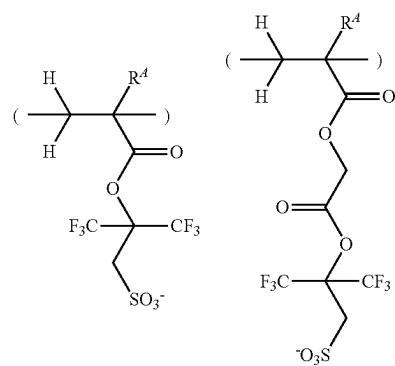
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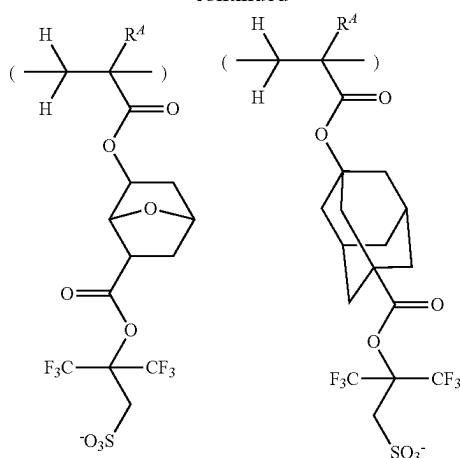
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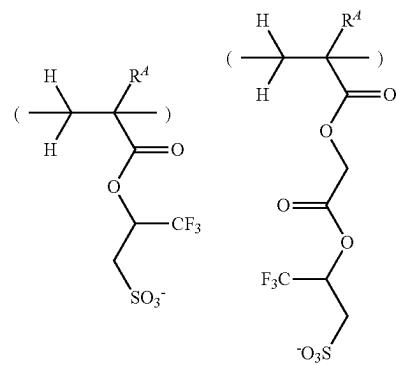
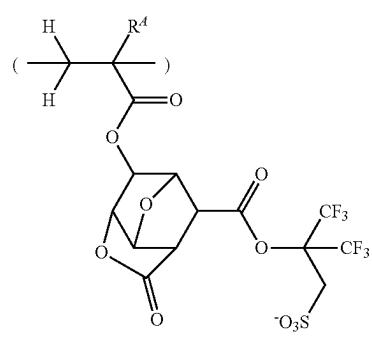
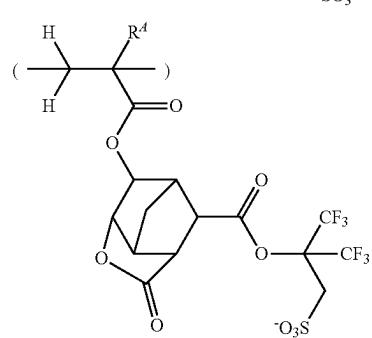
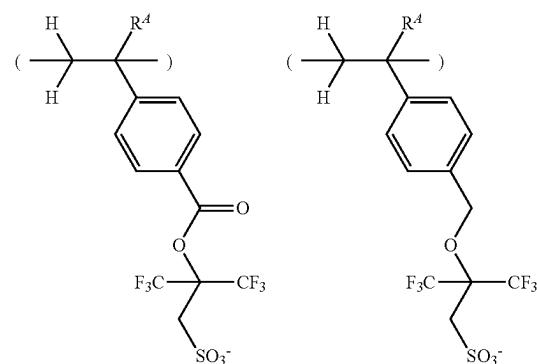
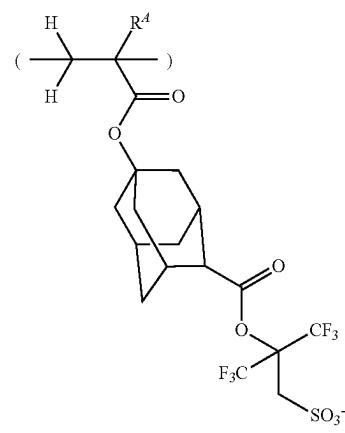
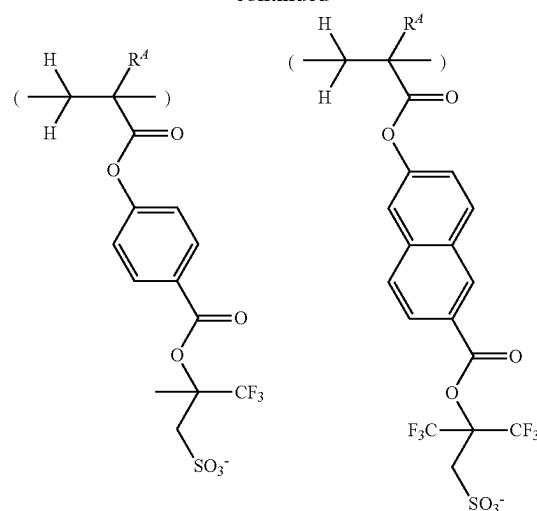
[0232] Examples of the anion in repeat unit (6) are shown below, but not limited thereto. R^A is as defined above.



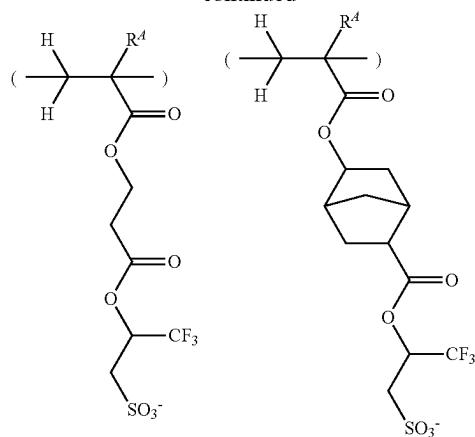
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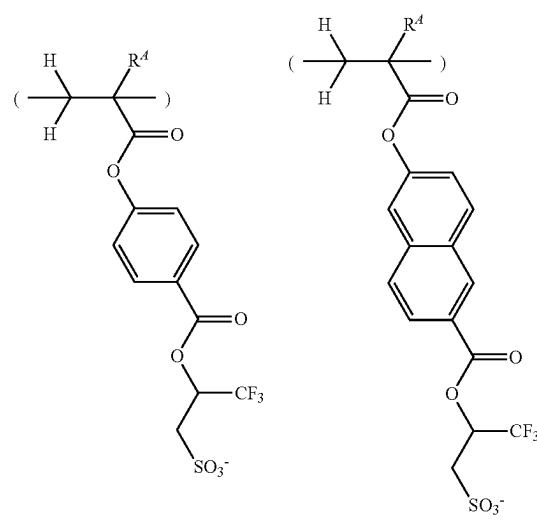
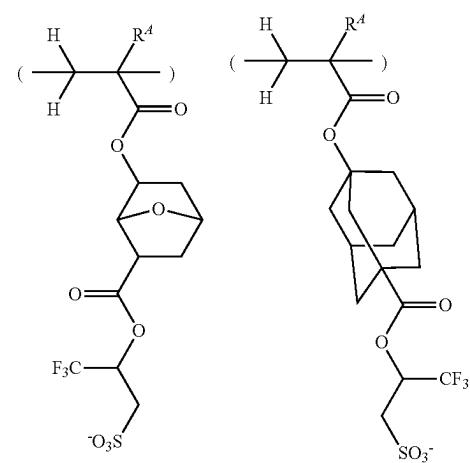
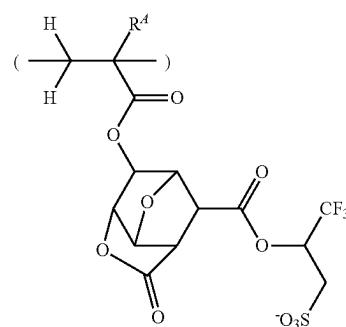
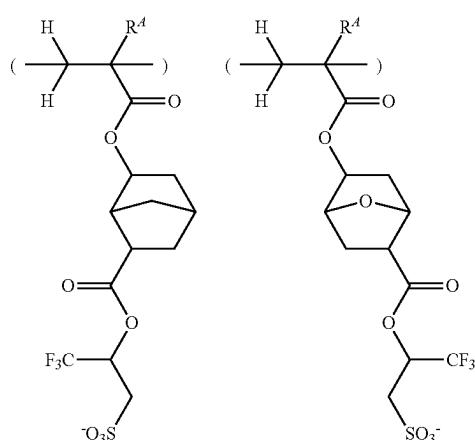
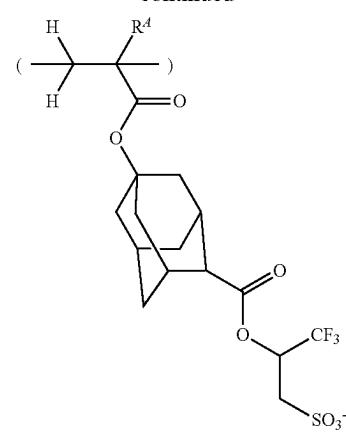
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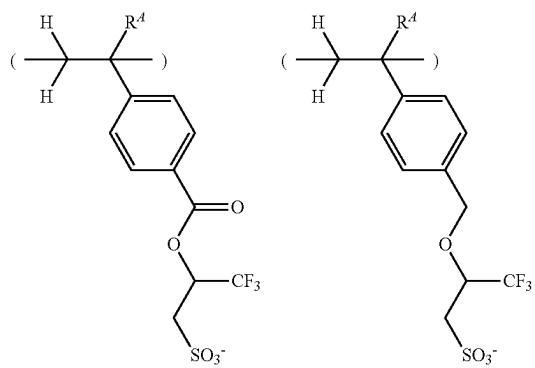
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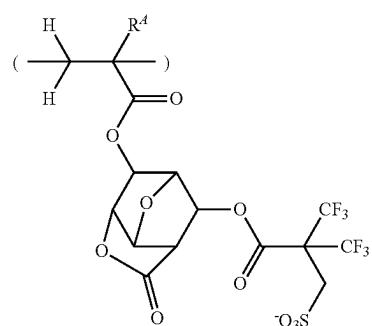
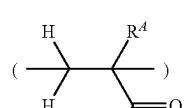
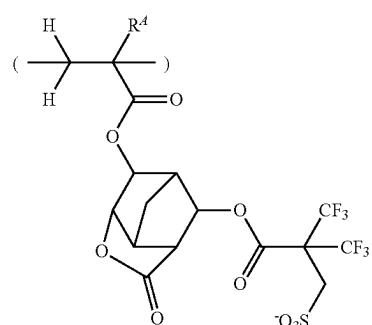
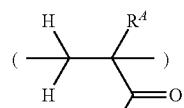
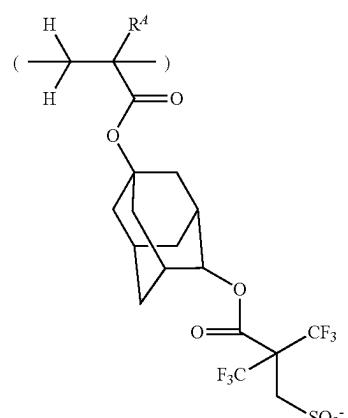
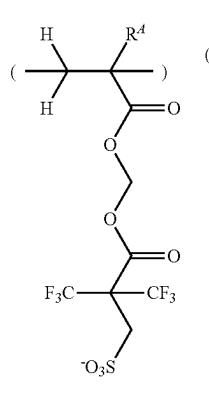
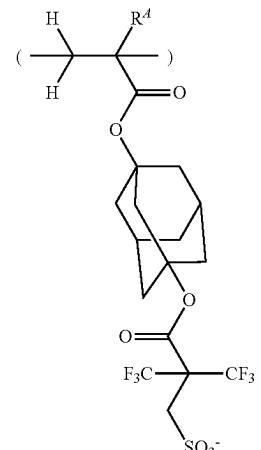
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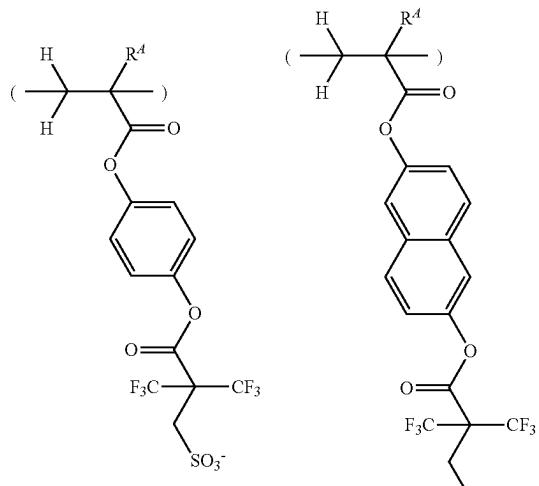
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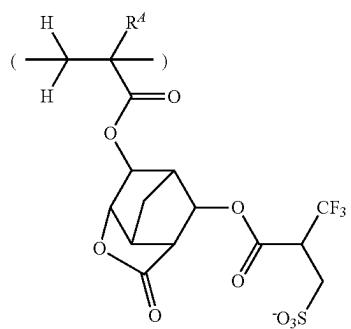
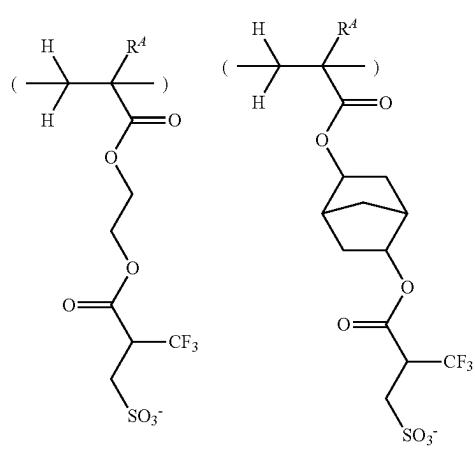
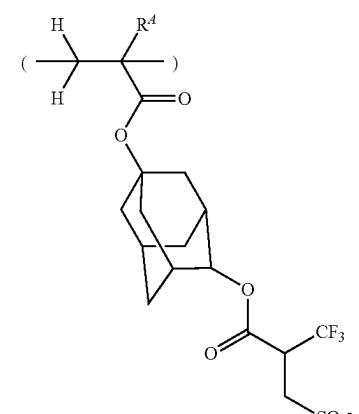
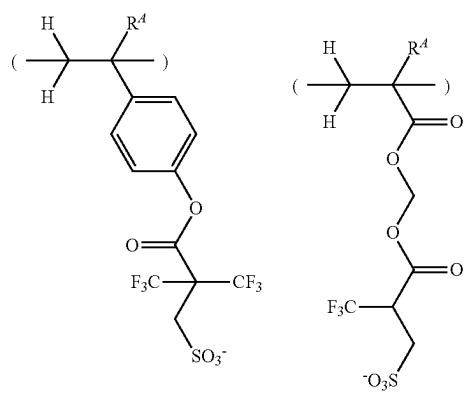
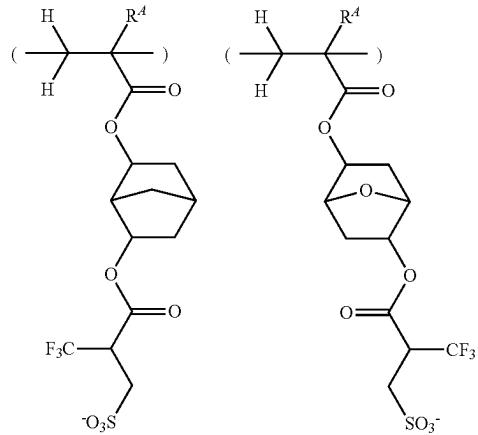
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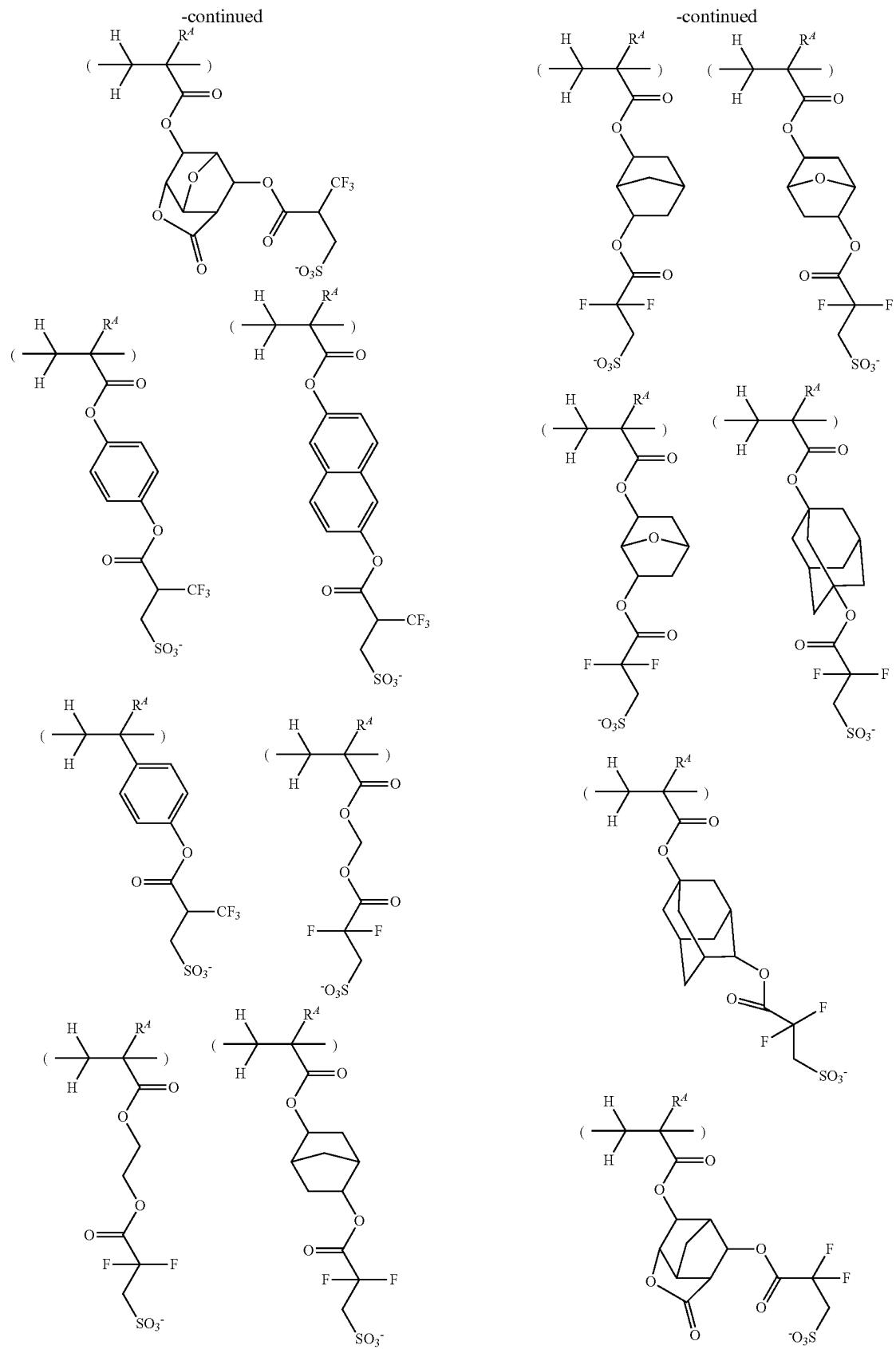


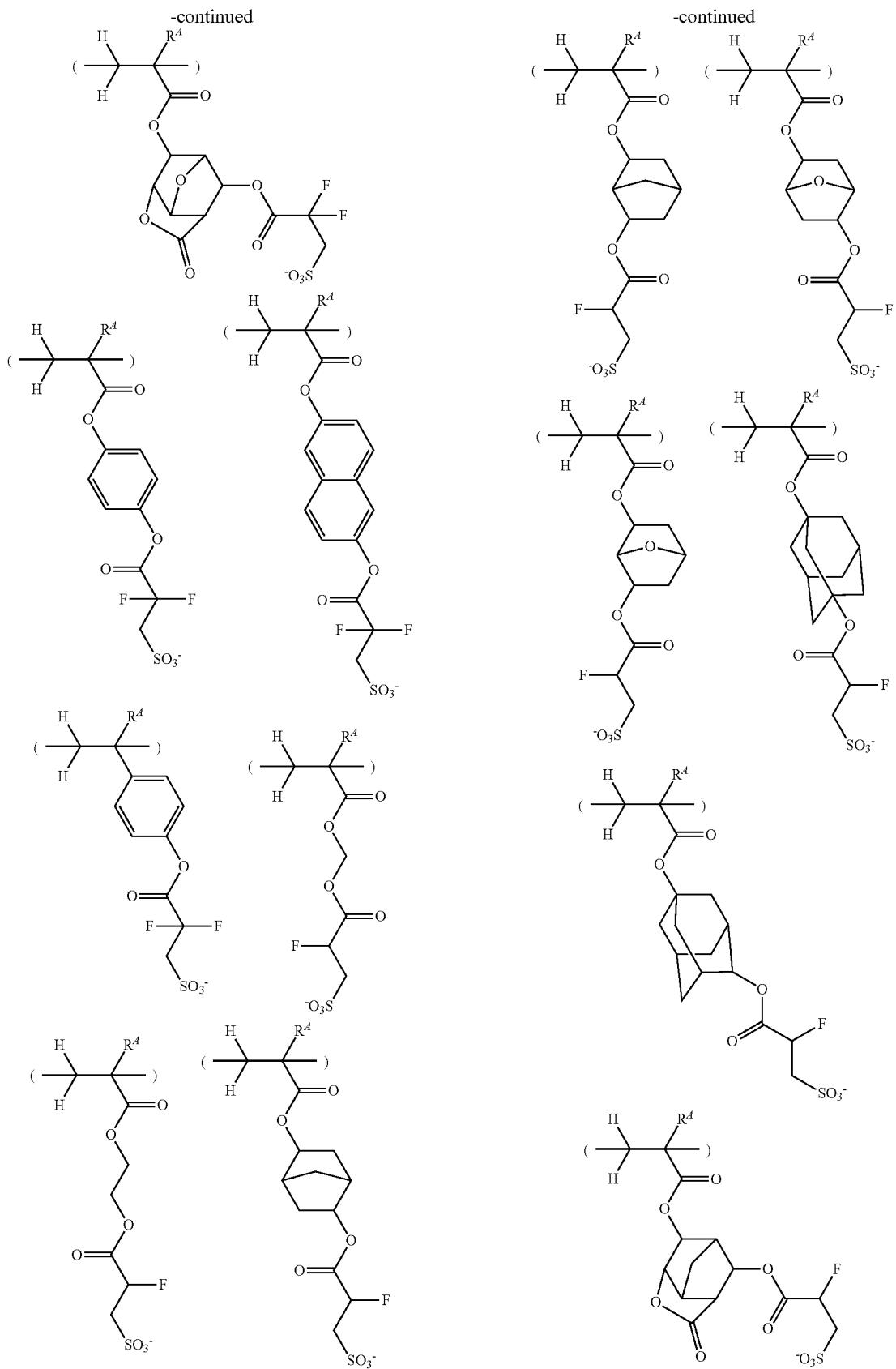
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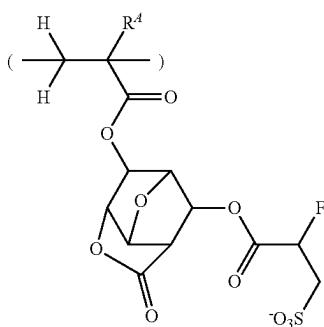
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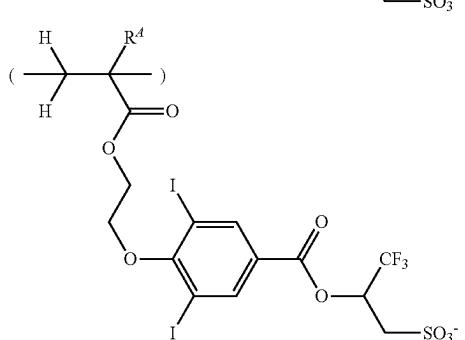
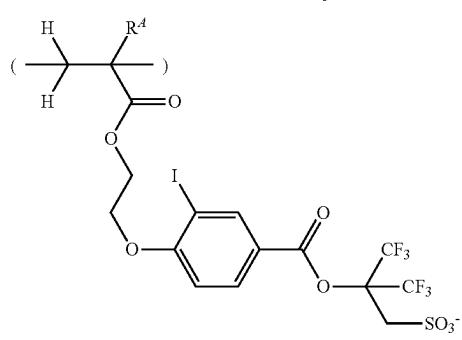
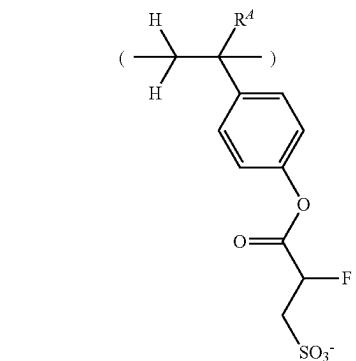
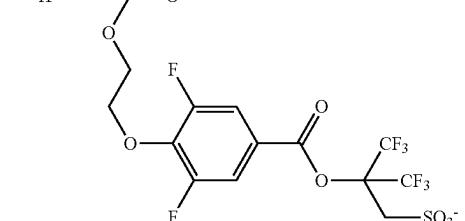
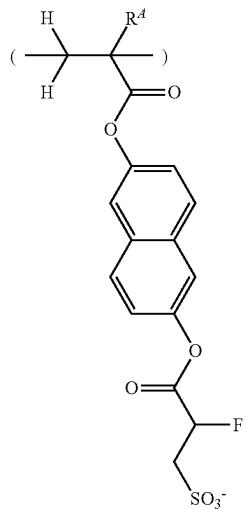
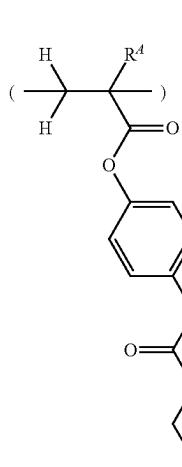
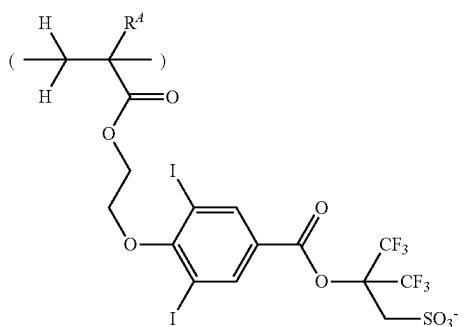




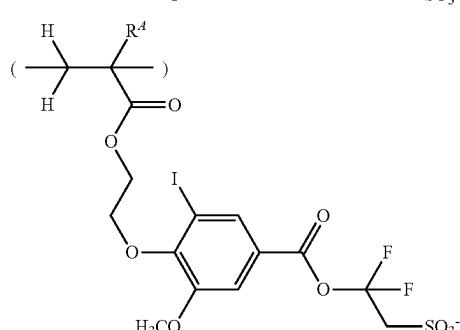
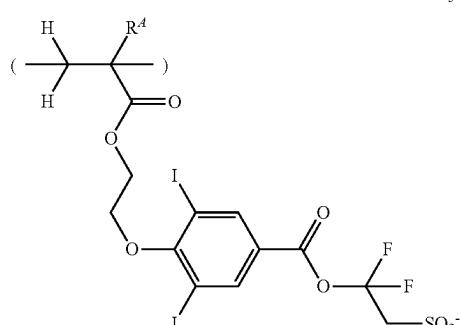
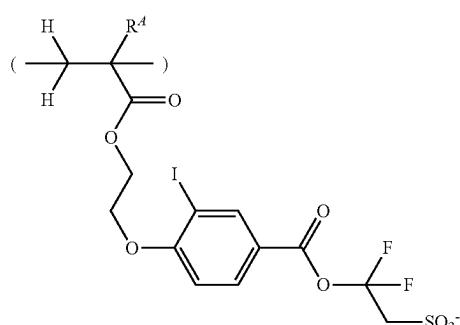
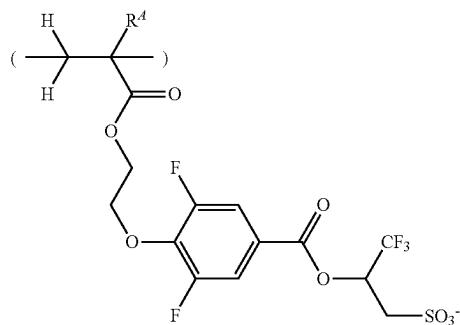
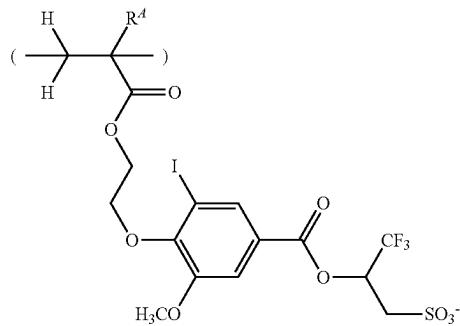
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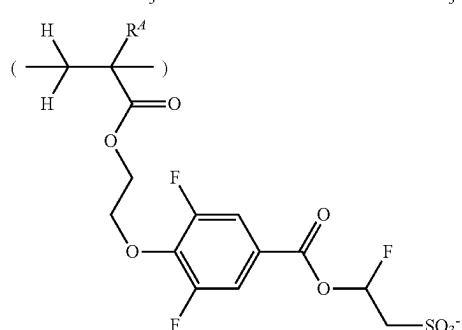
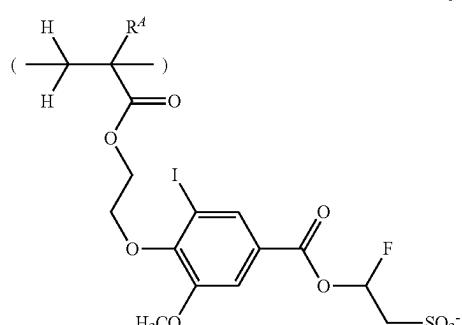
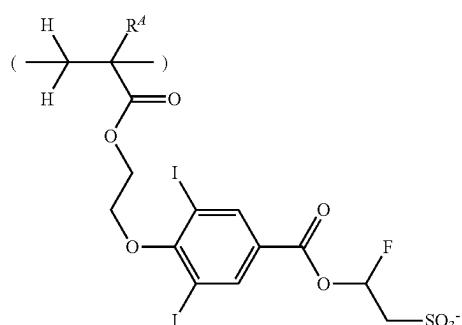
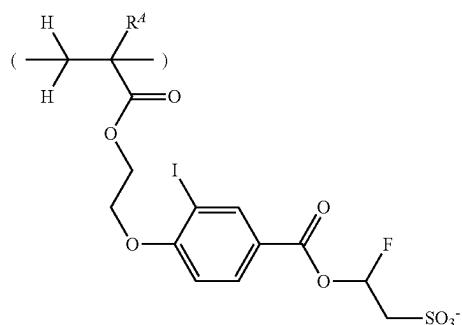
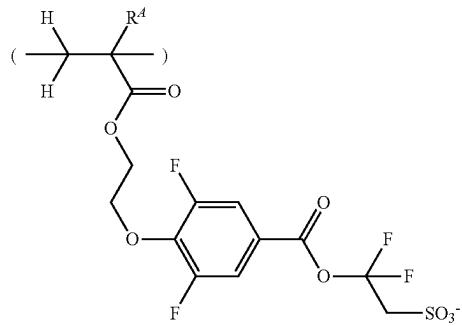
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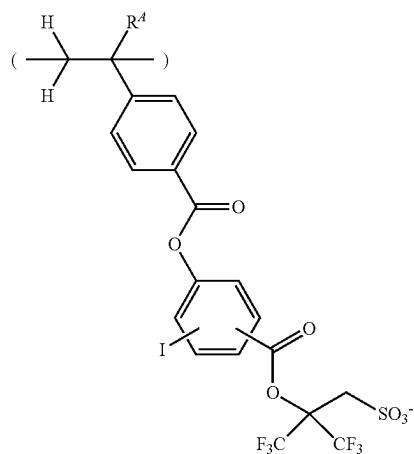
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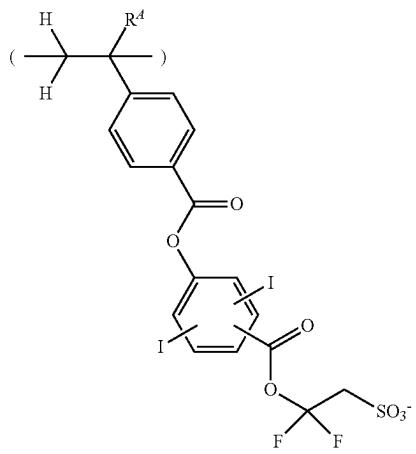
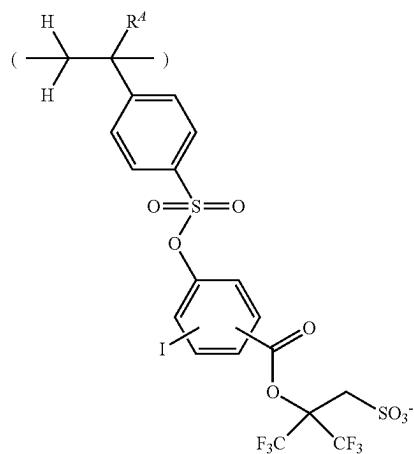
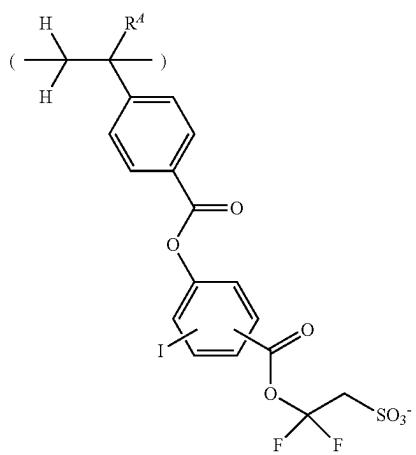
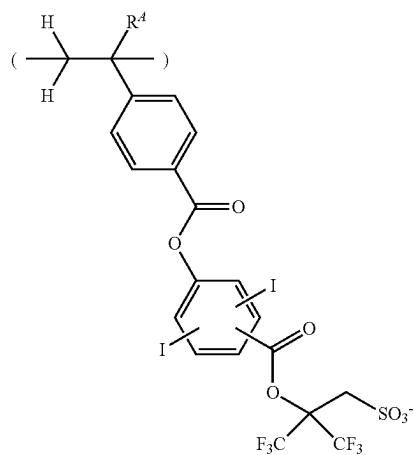
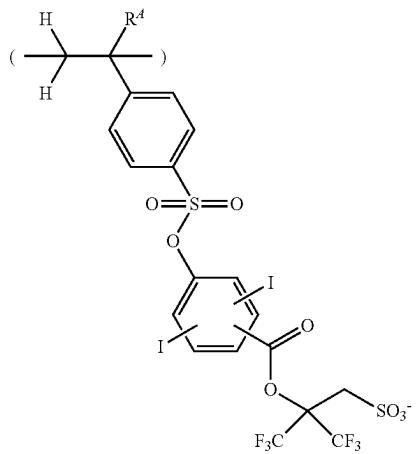
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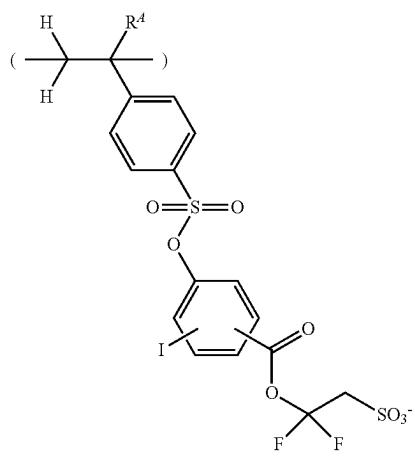
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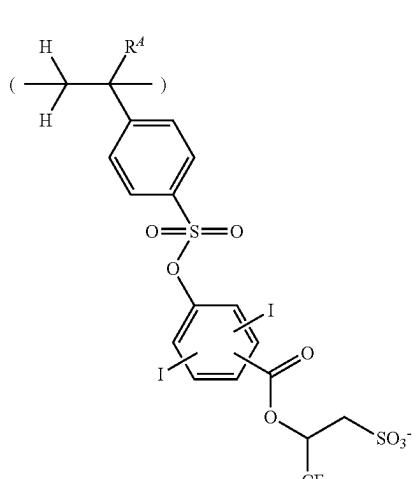
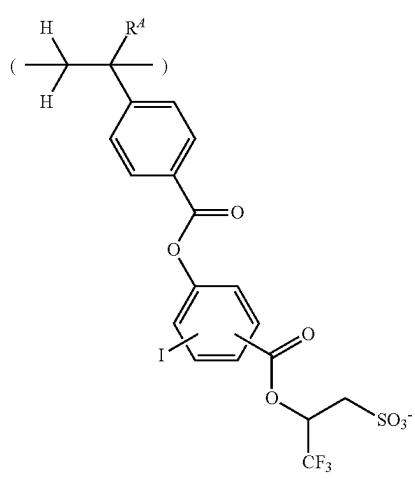
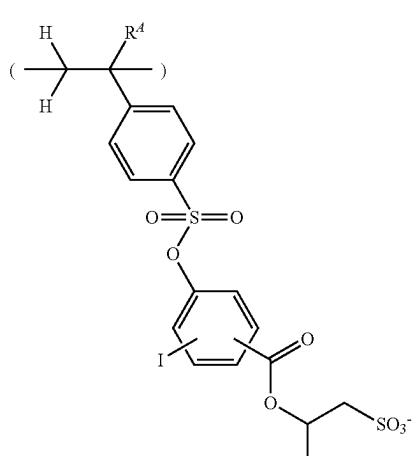
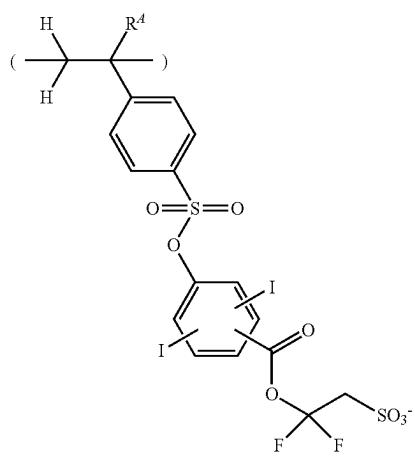
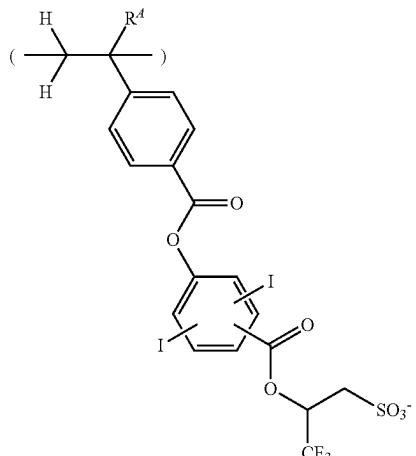
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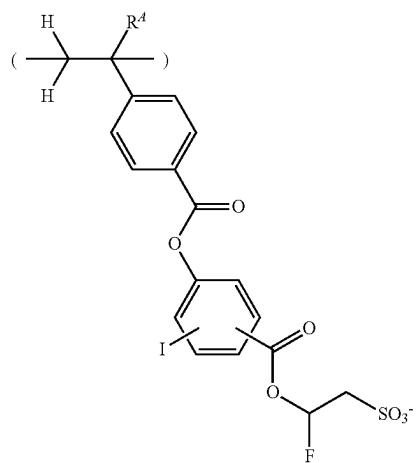
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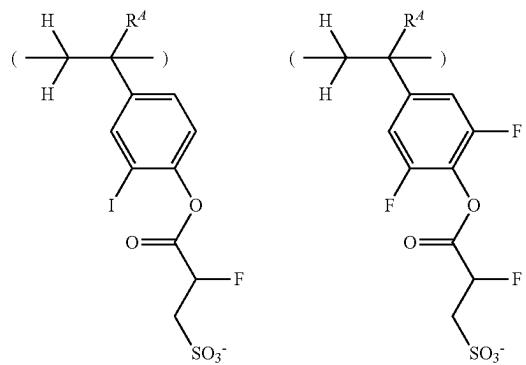
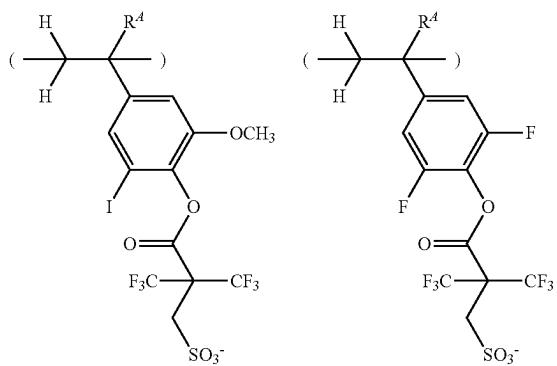
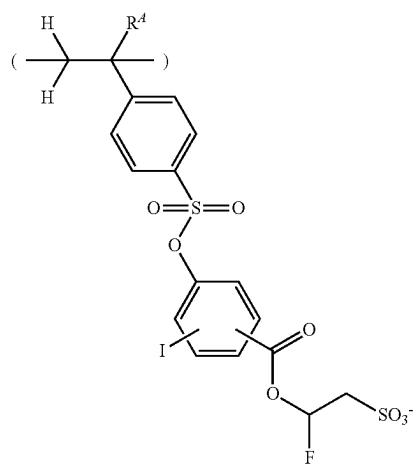
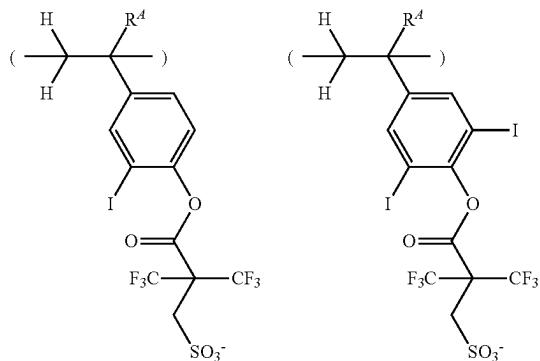
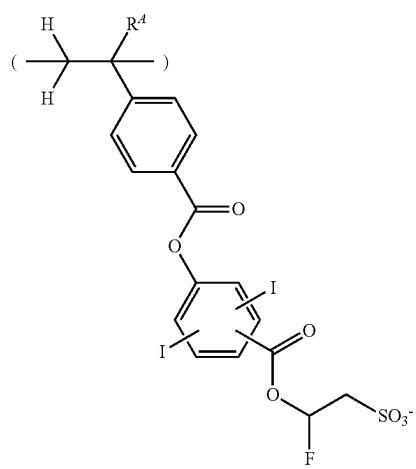
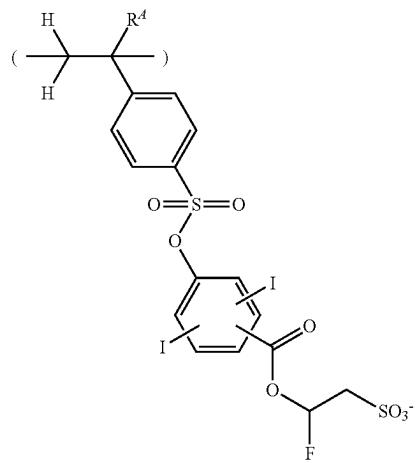
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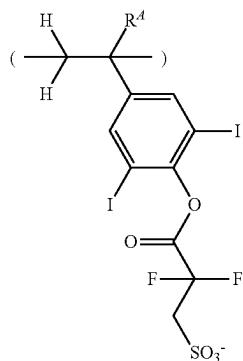
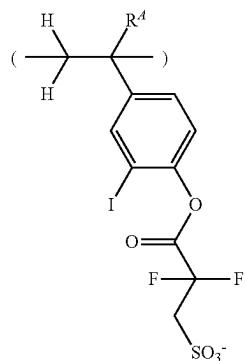
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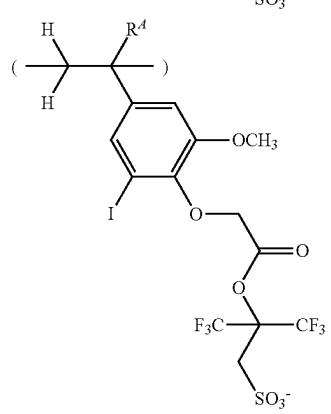
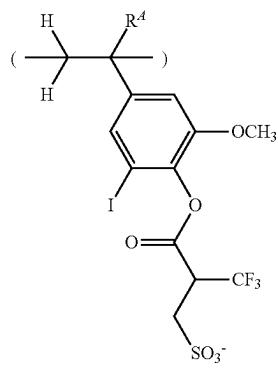
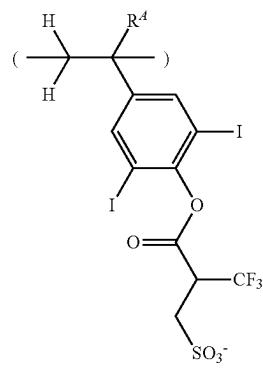
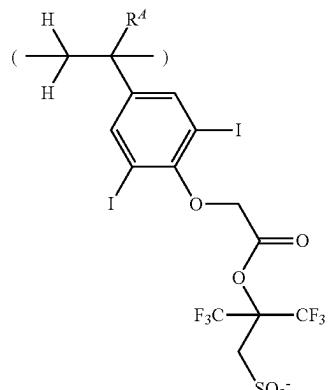
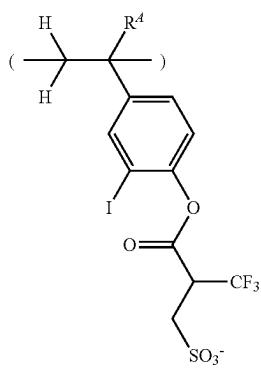
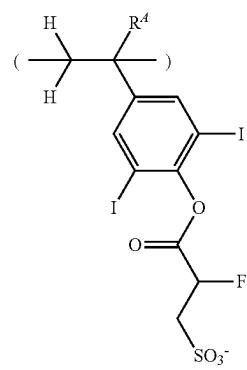
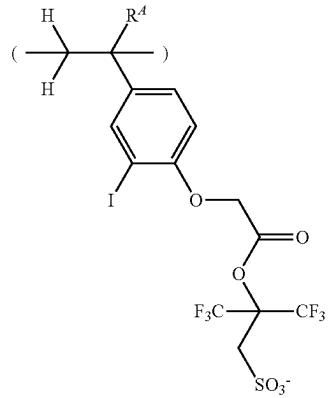
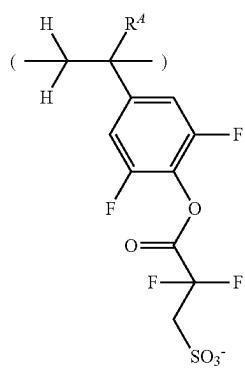
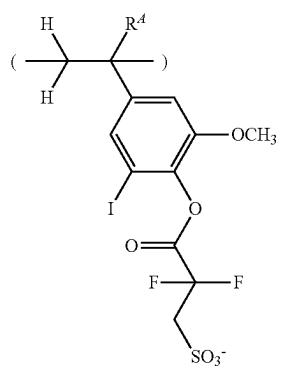
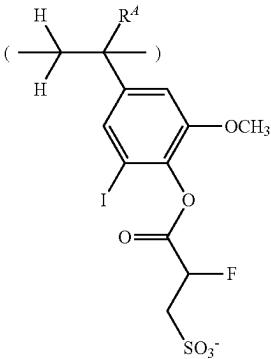
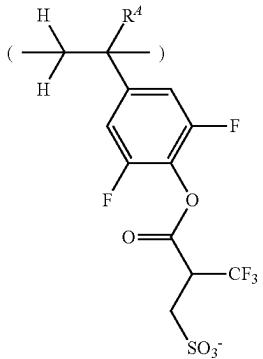
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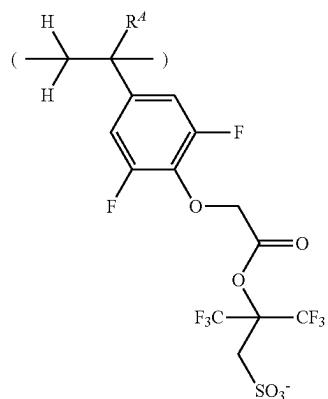
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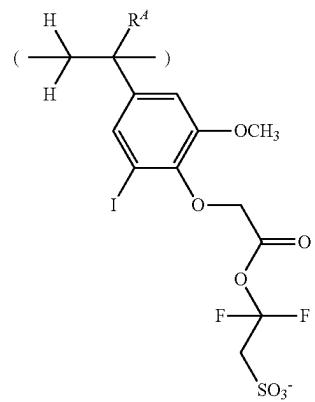
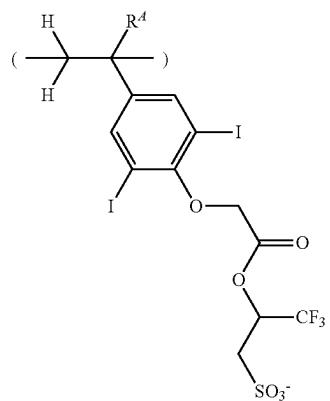
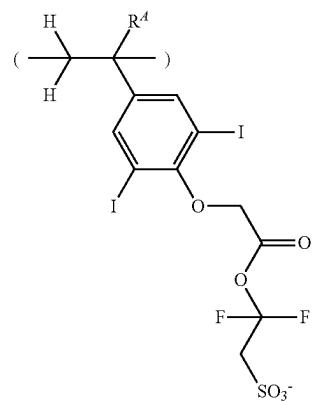
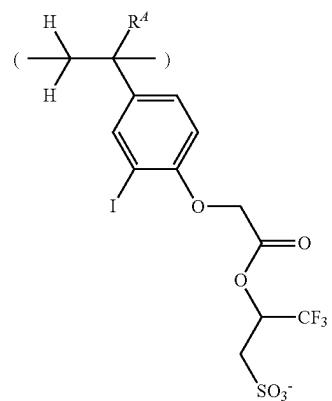
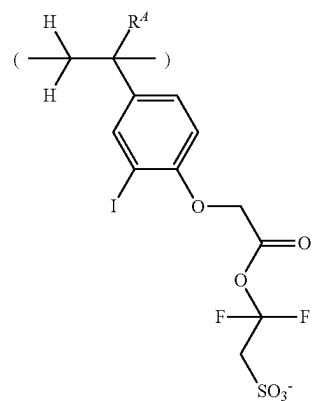
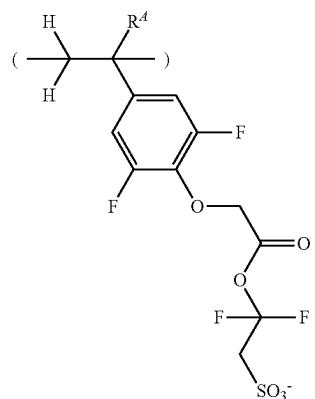
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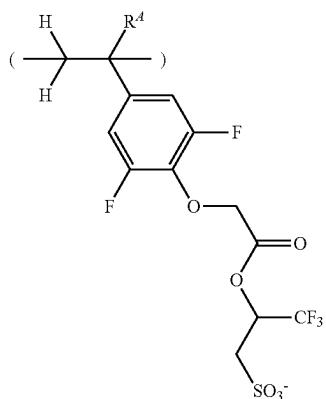
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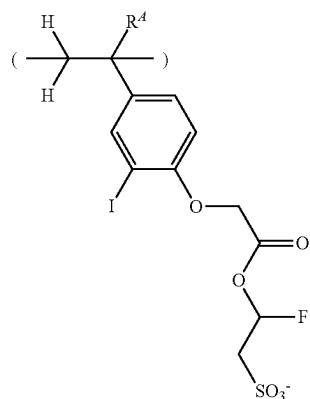
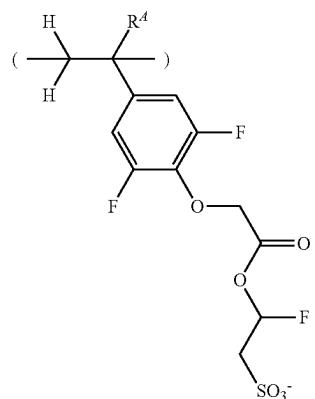
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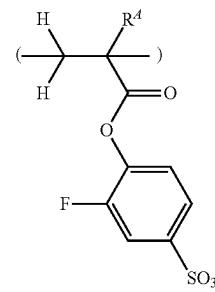
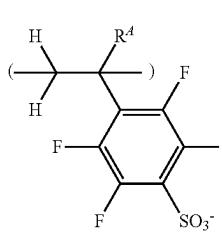
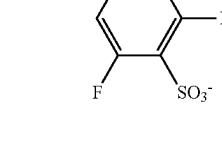
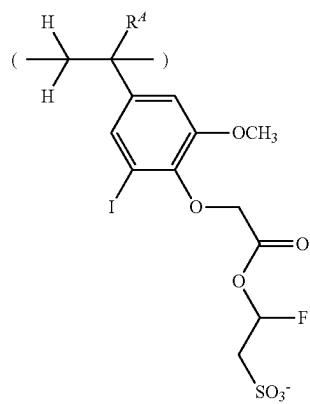
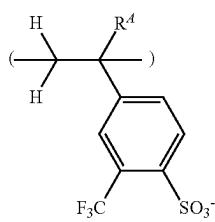
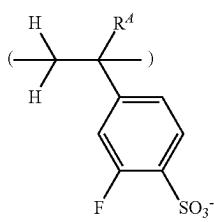
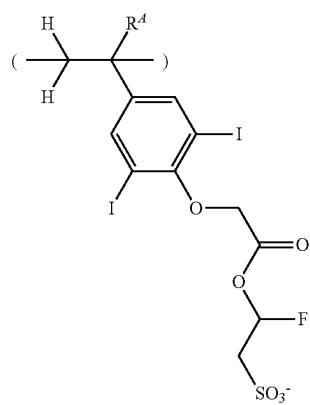
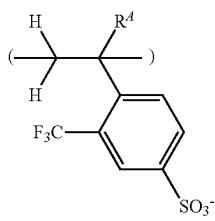
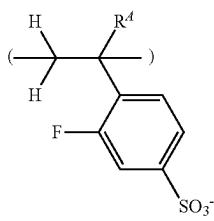
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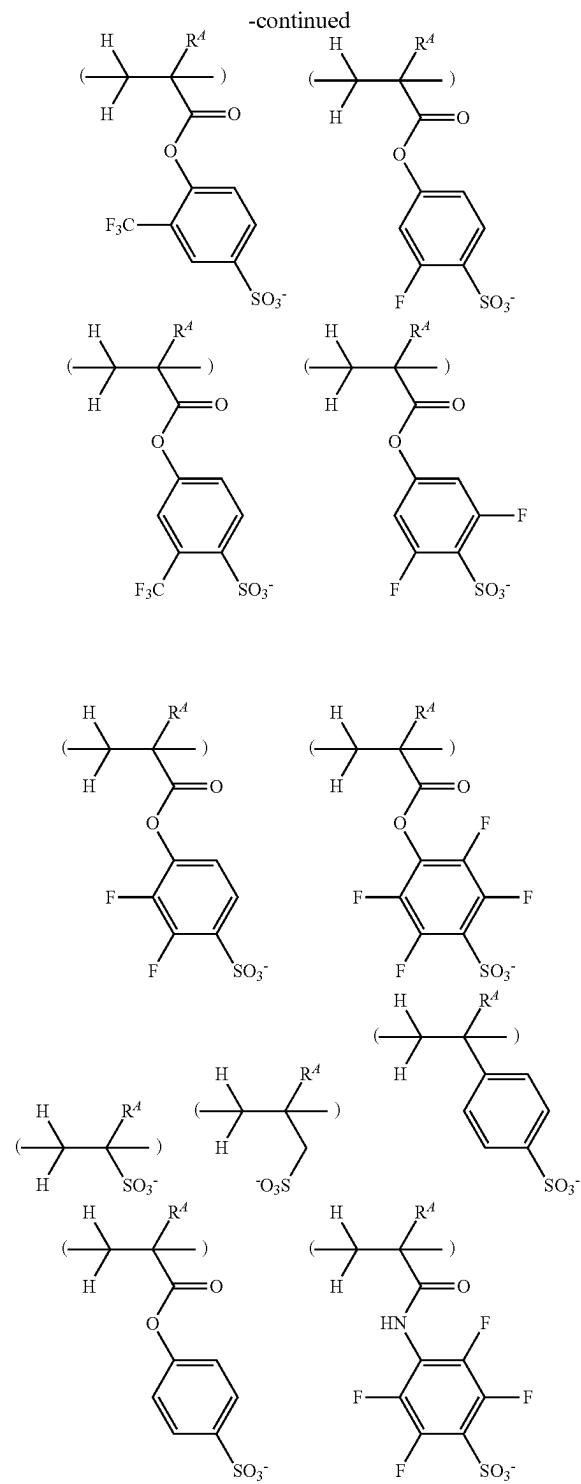


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[0233] Examples of the anion in repeat unit (c4) are shown below, but not limited thereto. R^{A} is as defined above.





[0234] In formulae (c2) to (c4), A^+ is an onium cation. Suitable onium cations include ammonium, sulfonium and iodonium cations, with the sulfonium and iodonium cations being preferred.

[0235] Preferred as the onium cation are sulfonium cations having the formula (cation-1) and iodonium cations having the formula (cation-2).

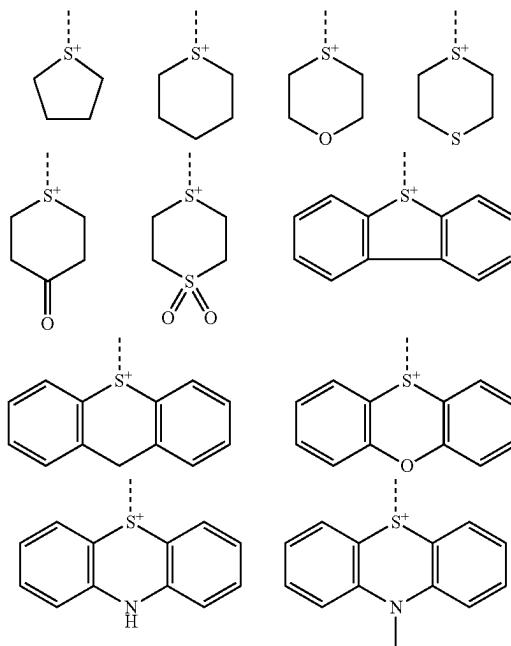


[0236] In formulae (cation-1) and (cation-2), R^{c1} to R^{c5} are each independently halogen or a C_1 - C_{30} hydrocarbyl group which may contain a heteroatom.

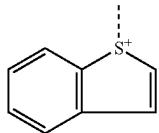
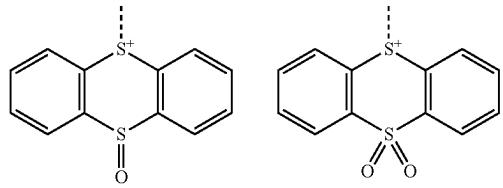
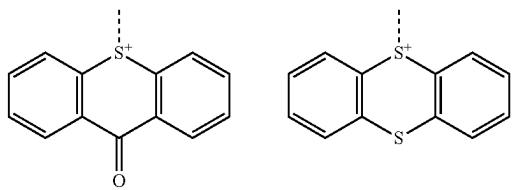
[0237] Suitable halogen atoms include fluorine, chlorine, bromine, and iodine.

[0238] The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C_1 - C_{30} alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, and tert-butyl; C_3 - C_{30} cyclic saturated hydrocarbyl groups such as cyclopropyl, cyclopentyl, cyclohexyl, cyclopropylmethyl, 4-methylcyclohexyl, cyclohexylmethyl, norbornyl, and adamantyl; C_2 - C_{30} alkenyl groups such as vinyl, allyl, propenyl, butenyl, and hexenyl; C_3 - C_{30} cyclic unsaturated hydrocarbyl groups such as cyclohexenyl; C_6 - C_{30} aryl groups such as phenyl, naphthyl, and thiophenyl; C_7 - C_{30} aralkyl groups such as benzyl, 1-phenylethyl, and 2-phenylethyl, and combinations thereof. Of these, aryl groups are preferred. In the hydrocarbyl group, some or all of the hydrogen atoms may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some constituent $—CH_2—$ may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy moiety, fluorine, chlorine, bromine, iodine, cyano moiety, nitro moiety, carbonyl moiety, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride ($—C(=O)—O—C(=O)—$) or haloalkyl moiety.

[0239] Also, R^{c1} and R^{c2} may bond together to form a ring with the sulfur atom to which they are attached. Examples of the ring are shown below.

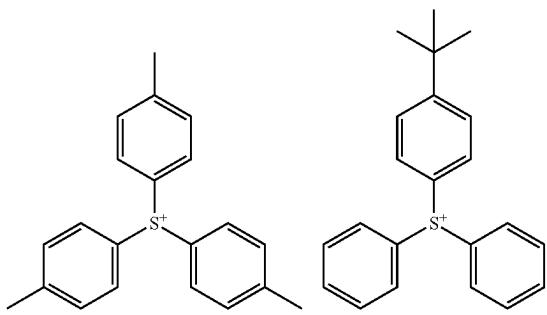
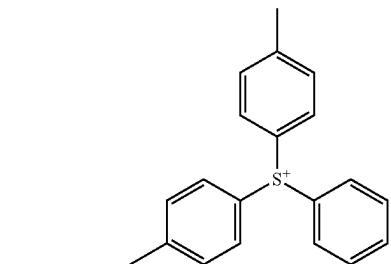
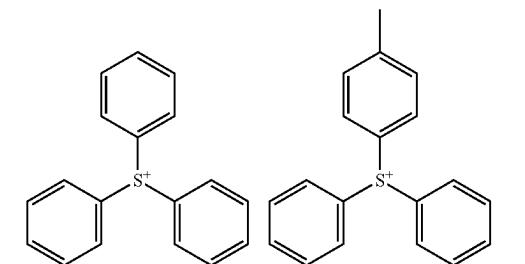


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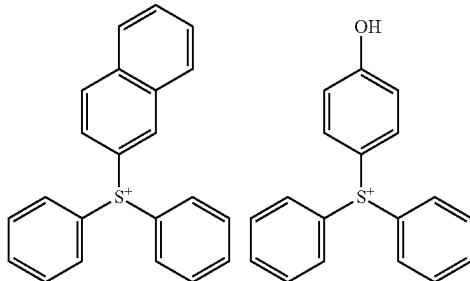
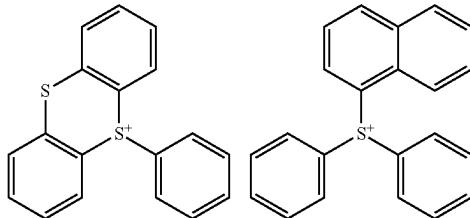
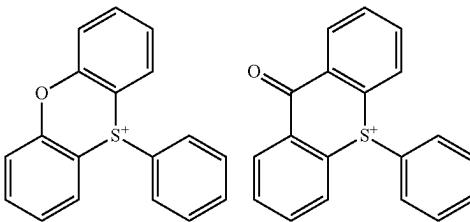
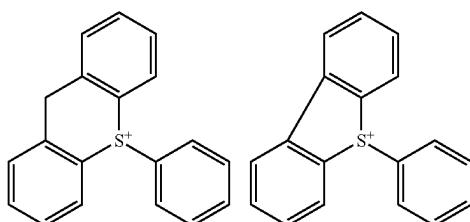
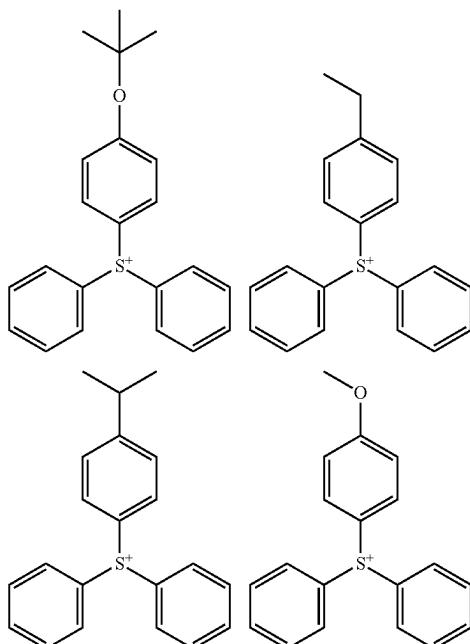


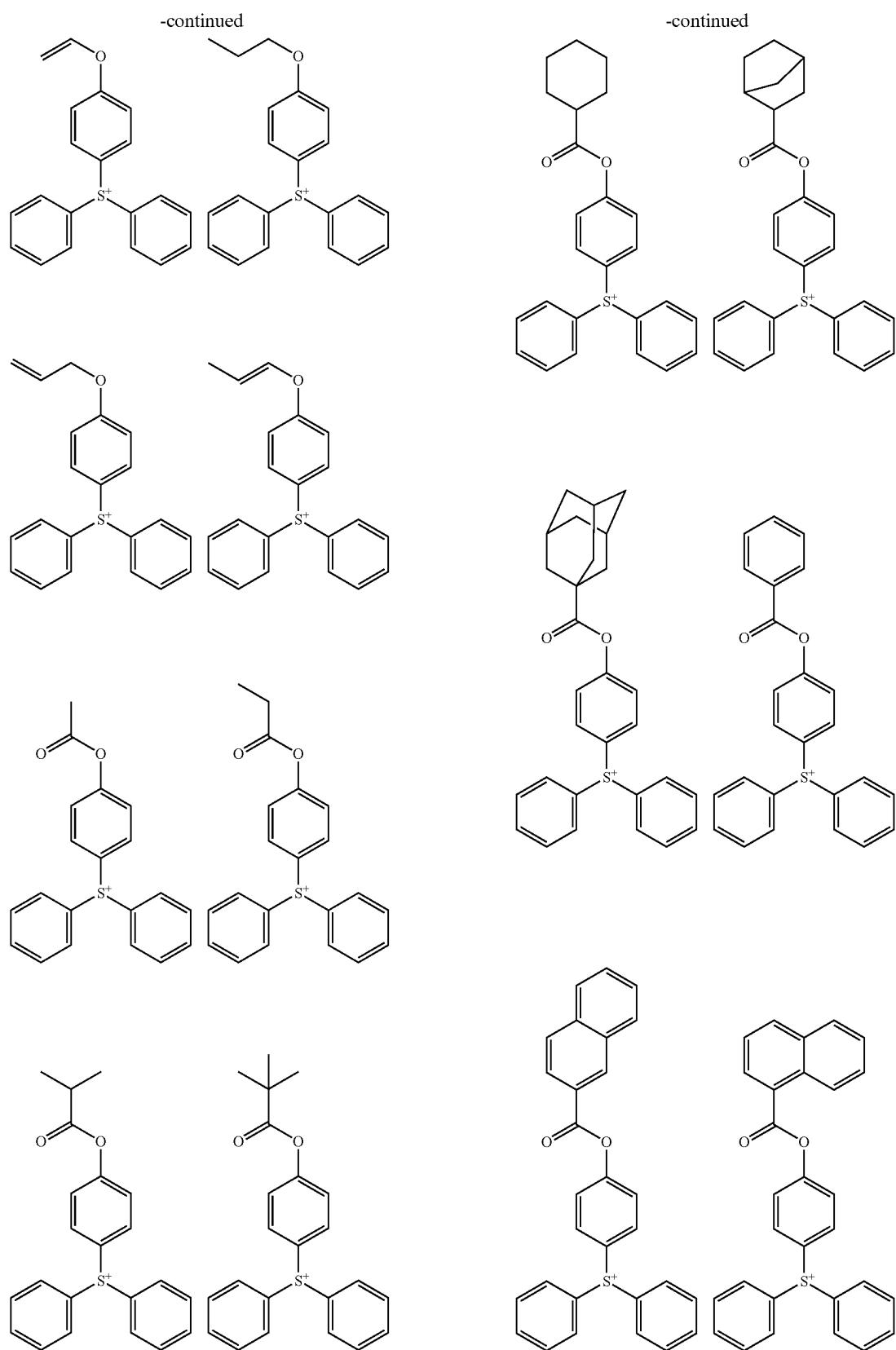
[0240] Herein the broken line designates a point of attachment to R^{c3}.

[0241] Examples of the sulfonium cation having formula (cation-1) are shown below, but not limited thereto.

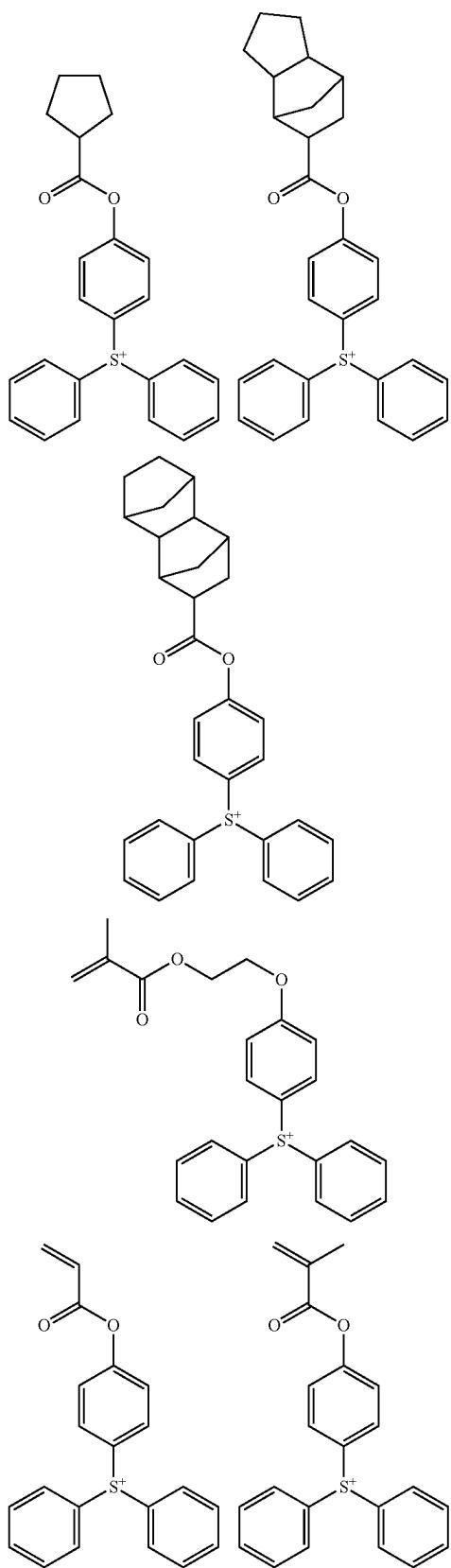


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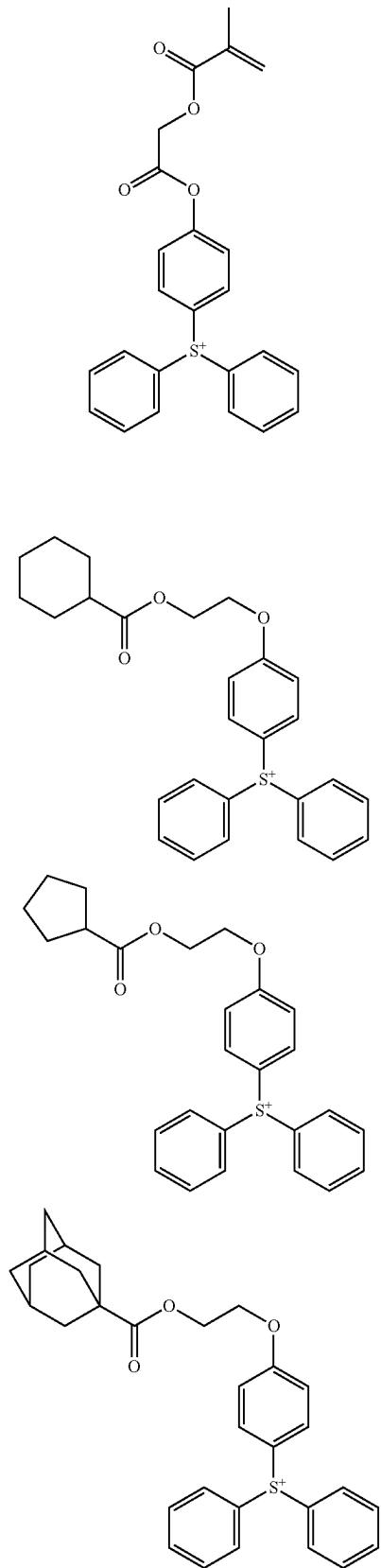




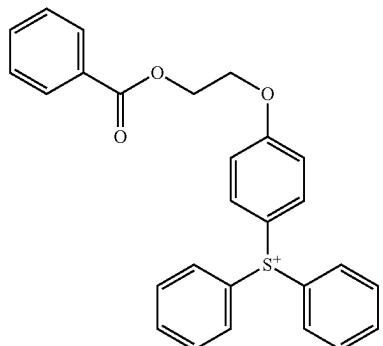
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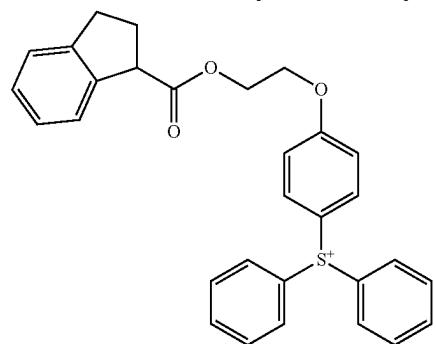
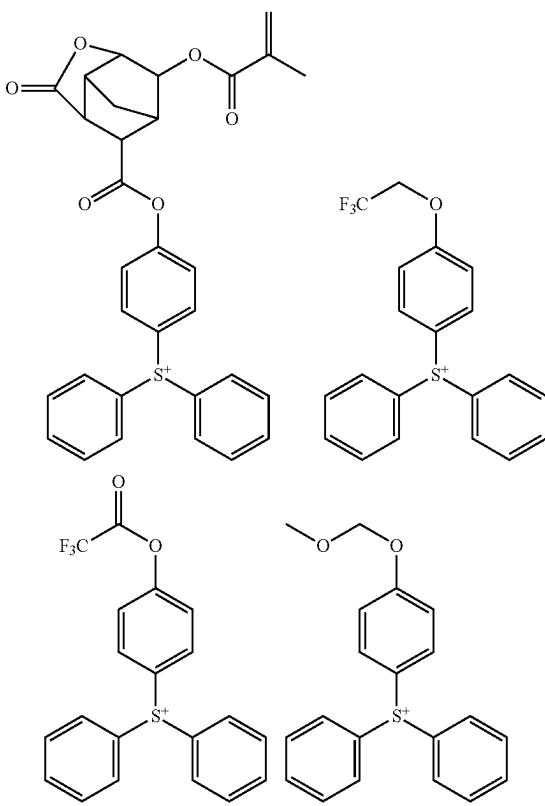
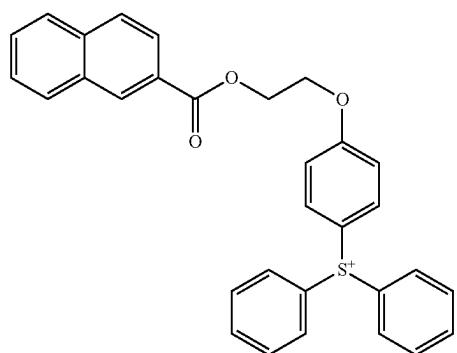
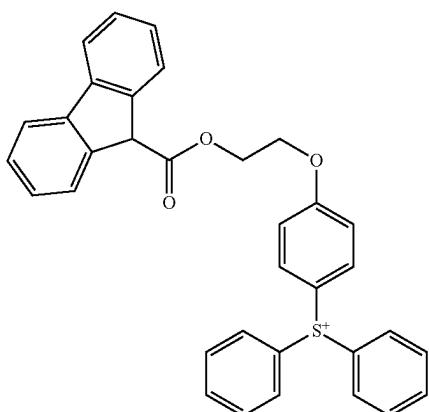
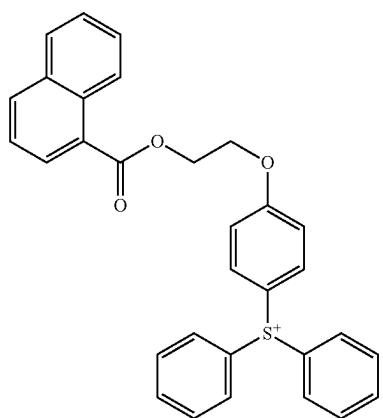
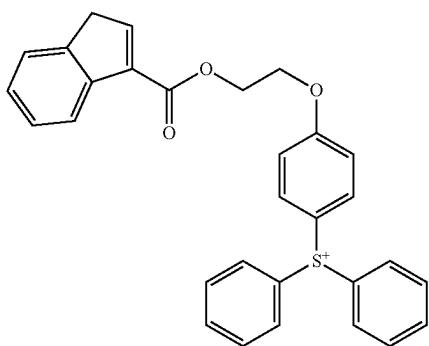
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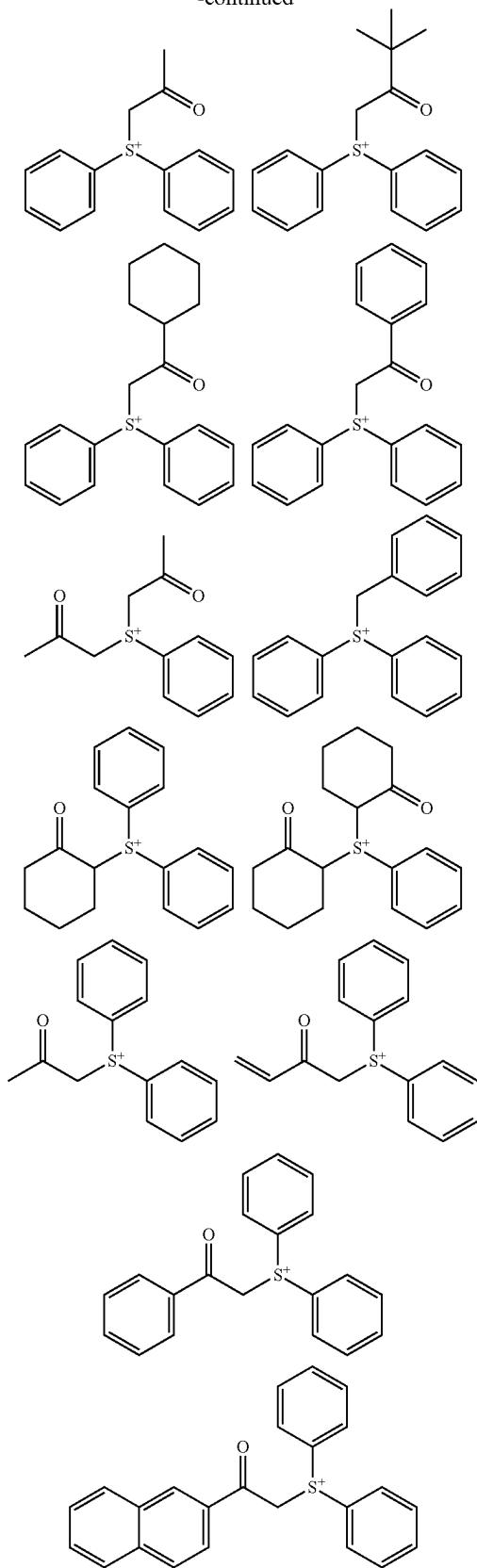
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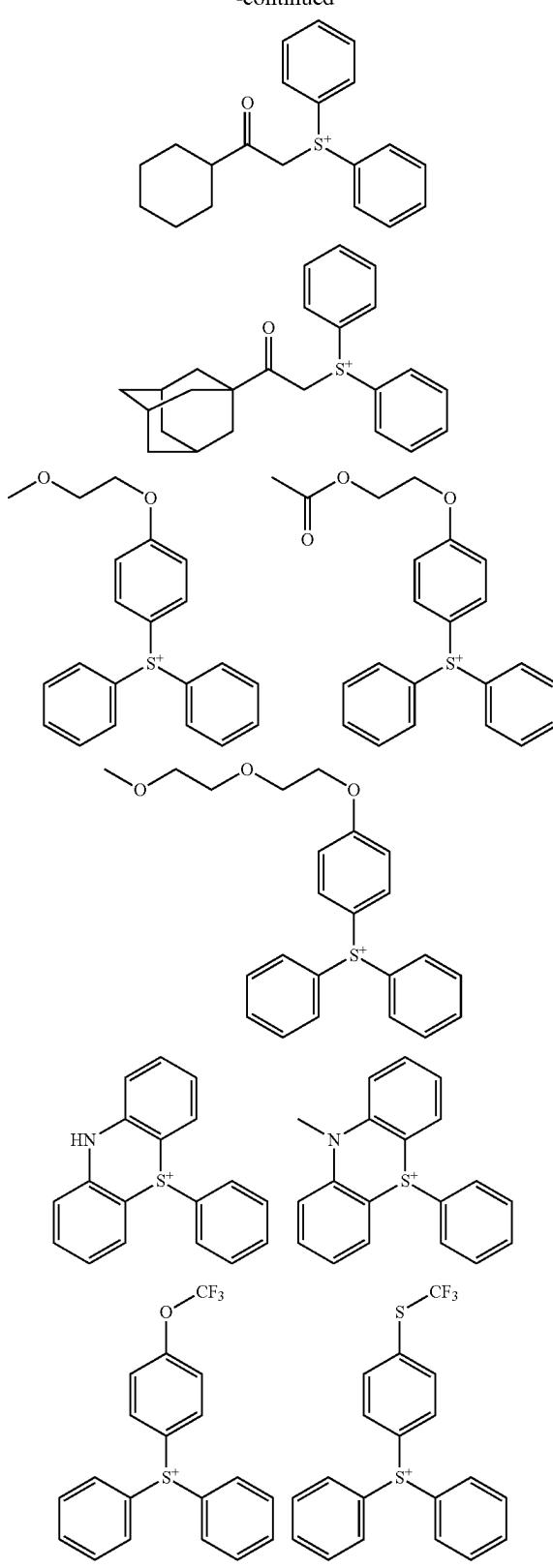
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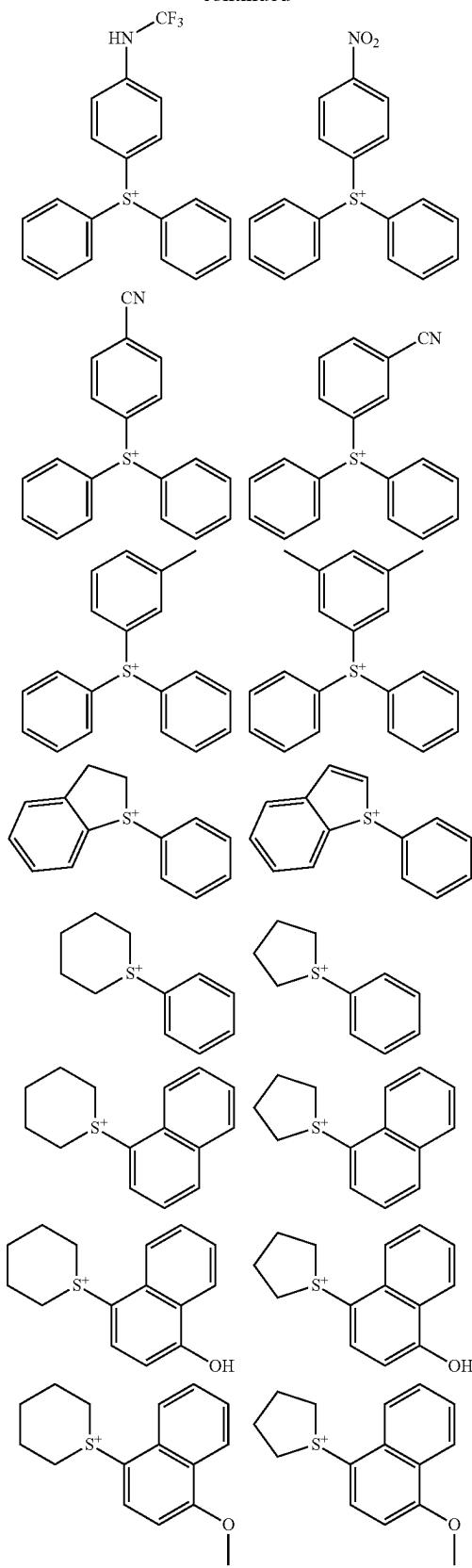
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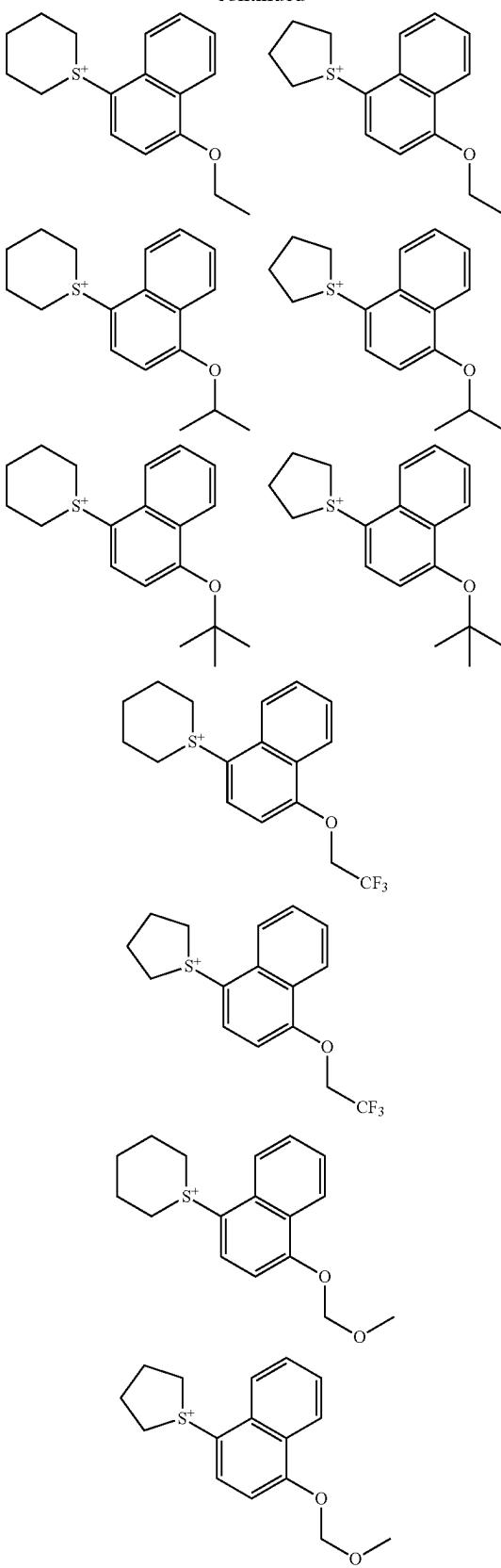
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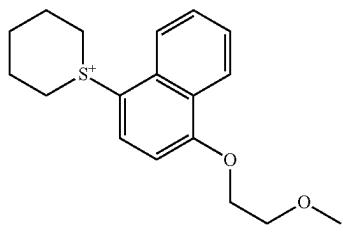
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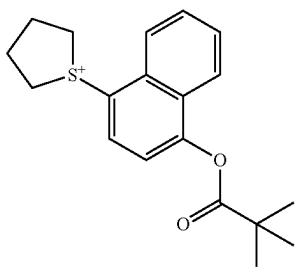
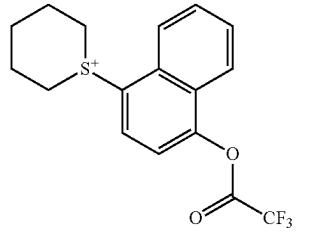
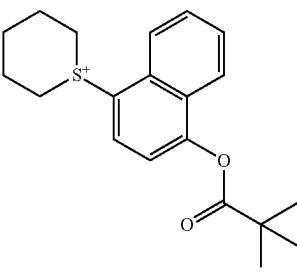
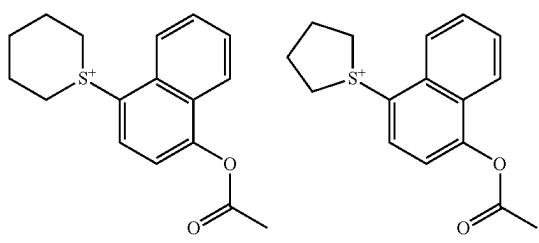
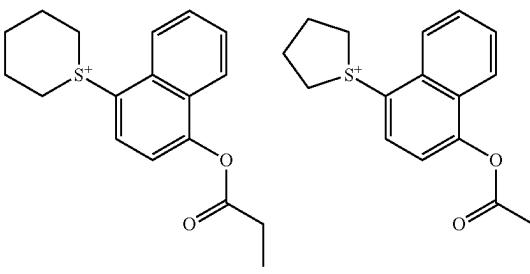
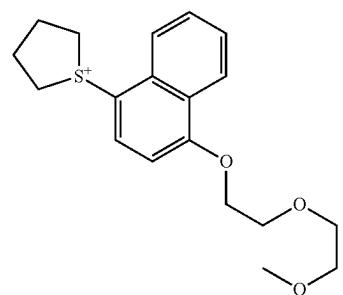
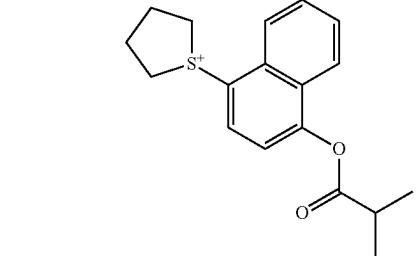
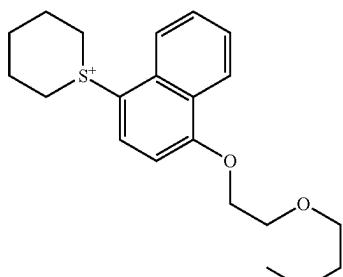
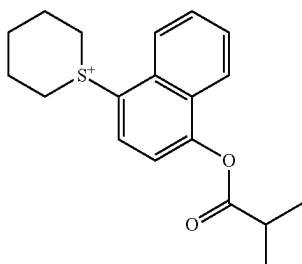
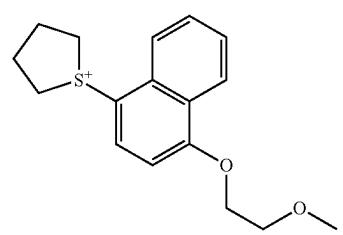
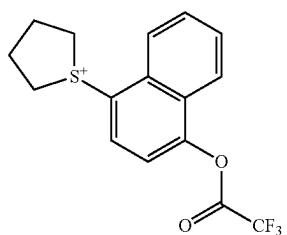
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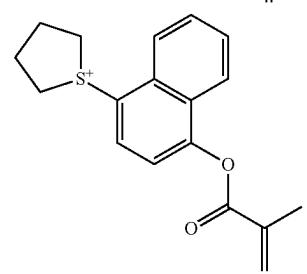
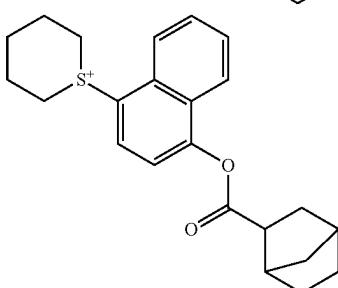
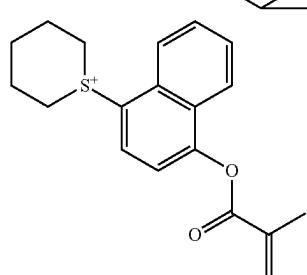
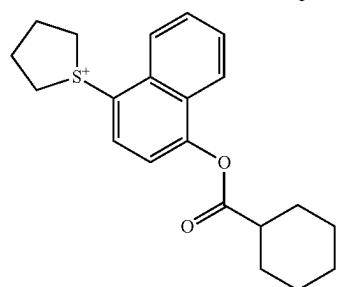
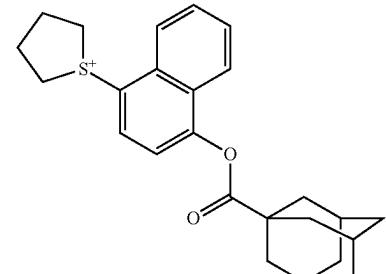
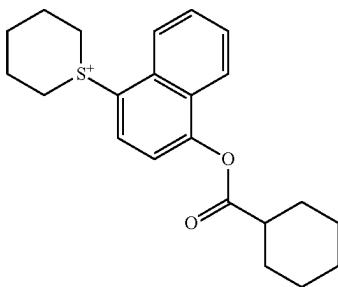
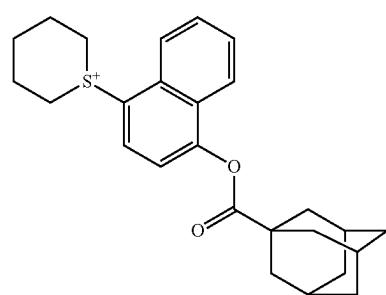
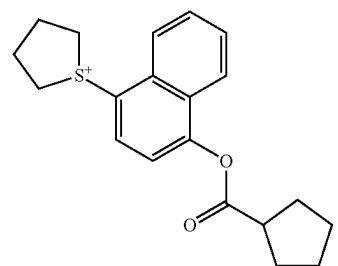
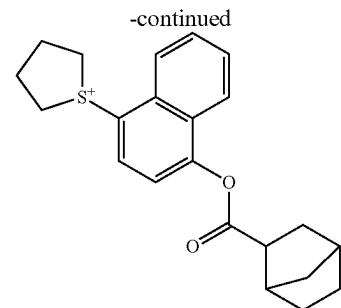
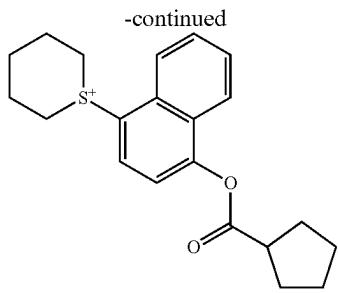


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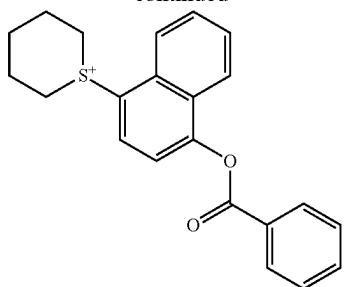


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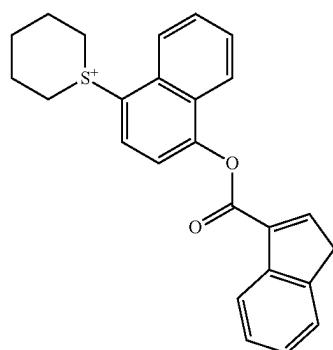
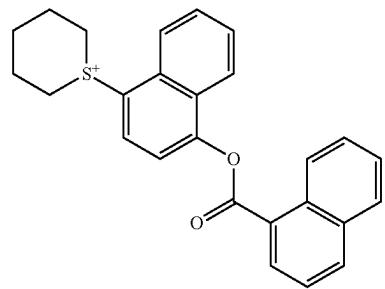
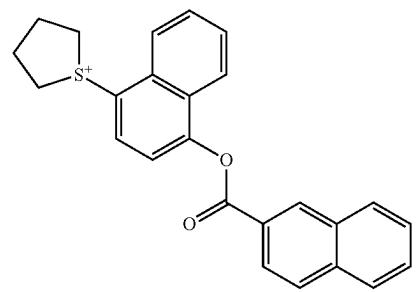
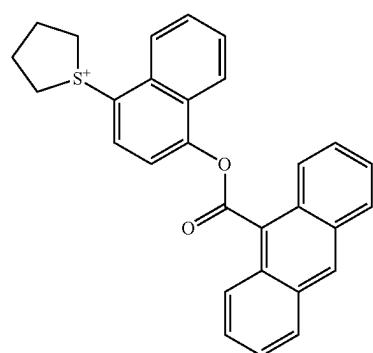
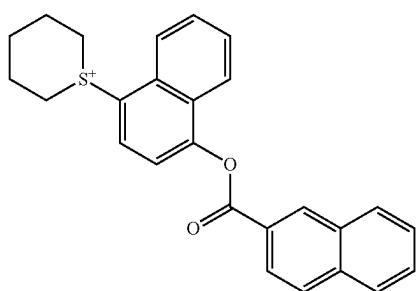
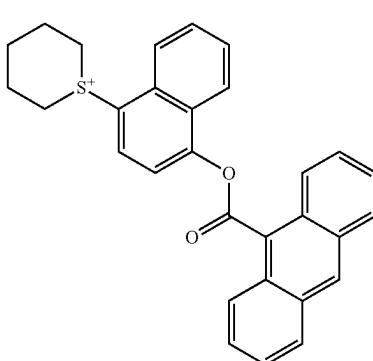
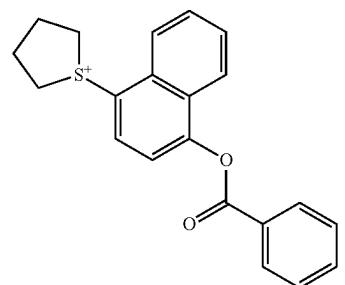
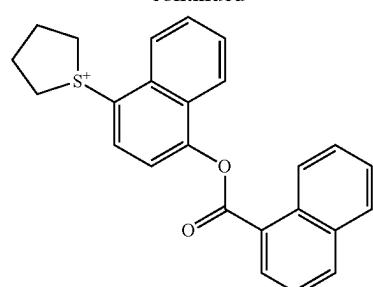




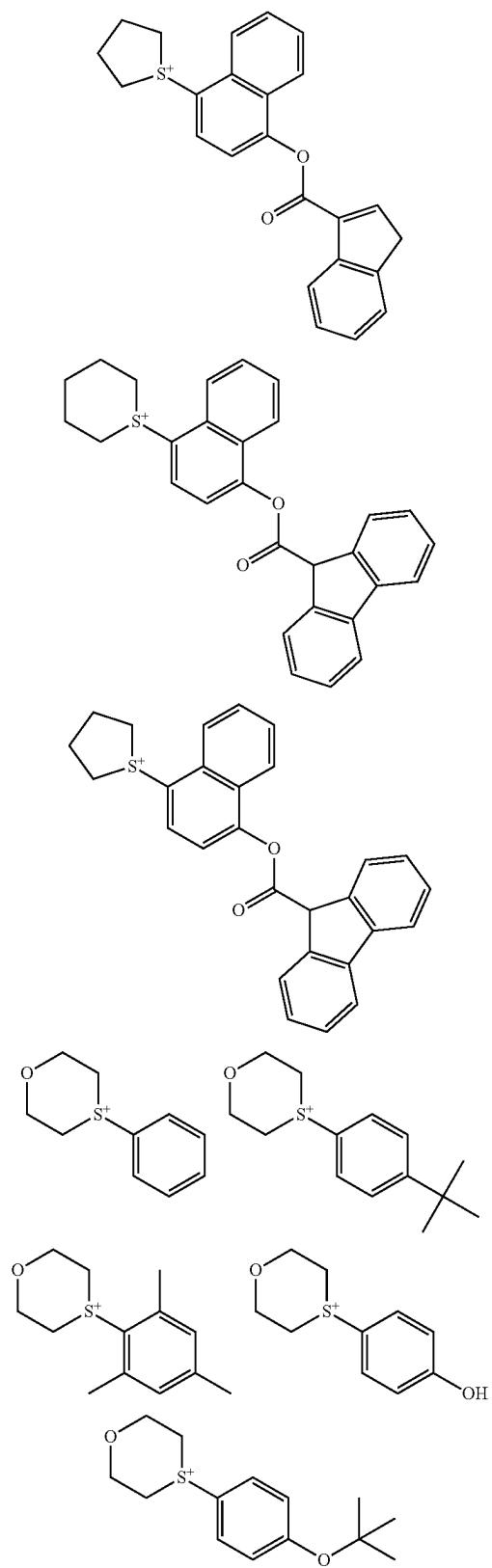
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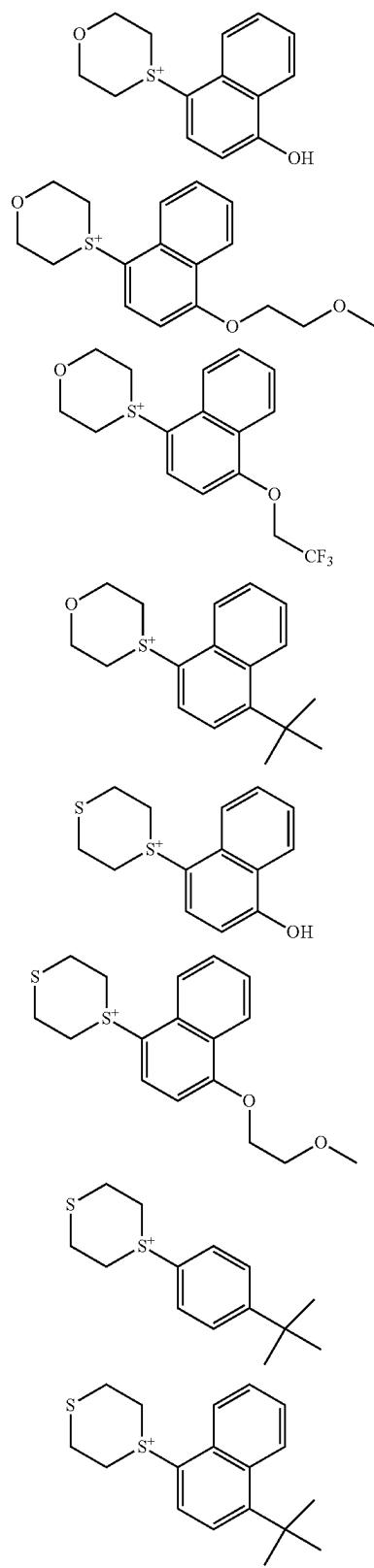
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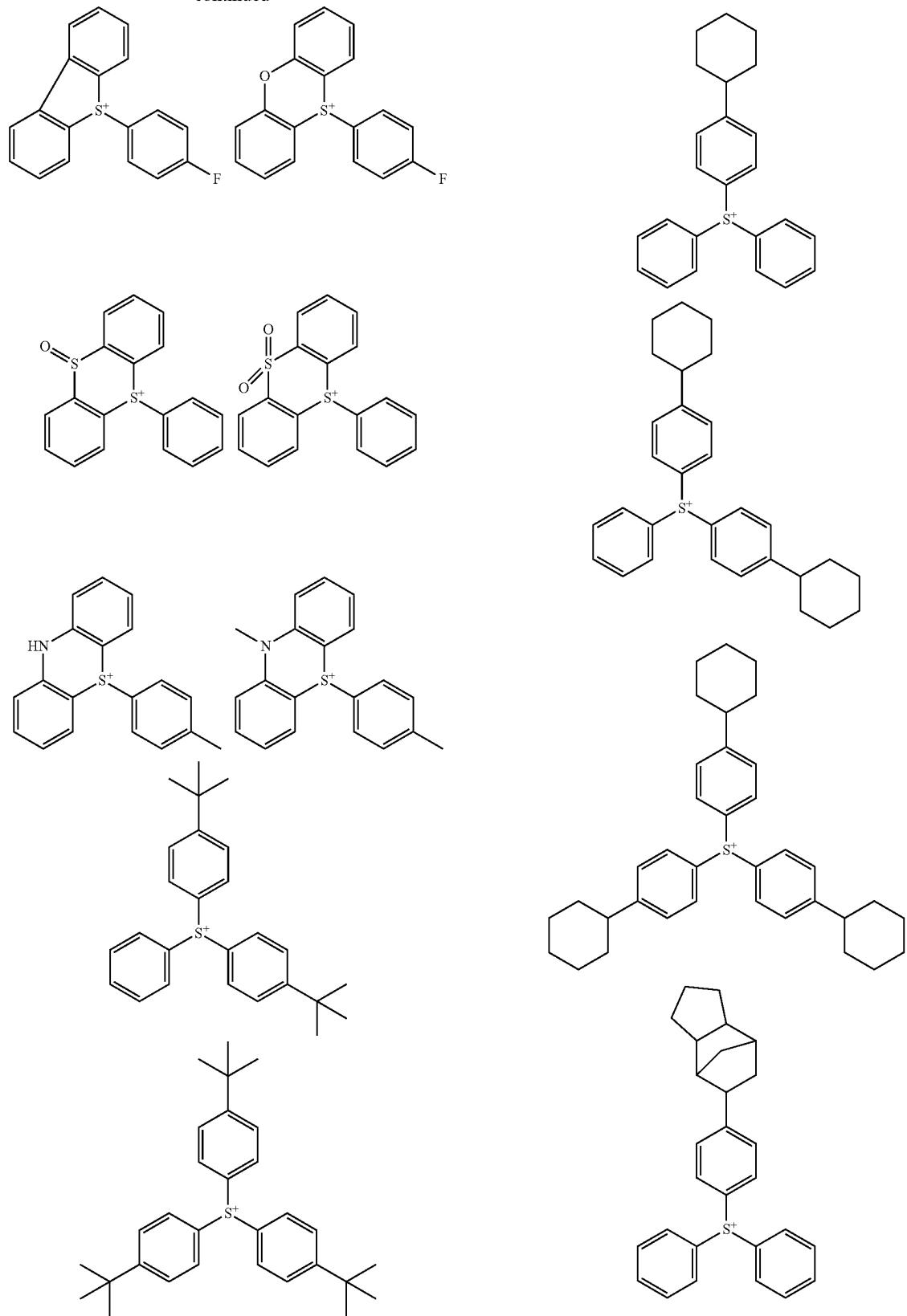
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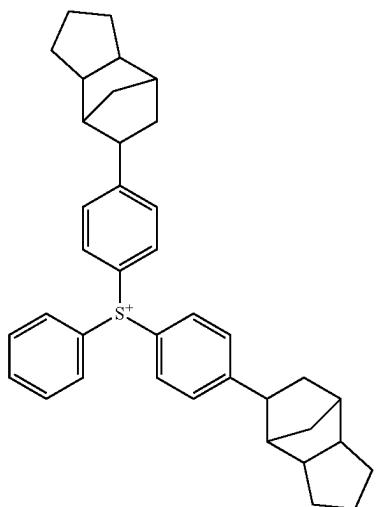
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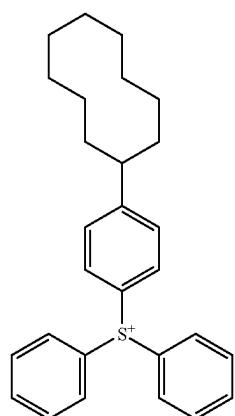
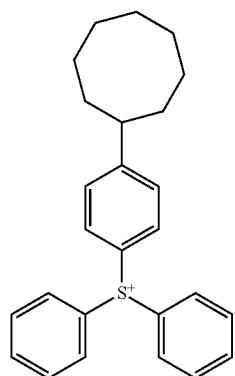
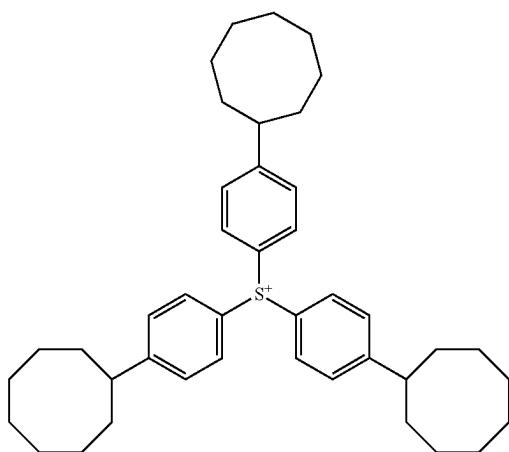
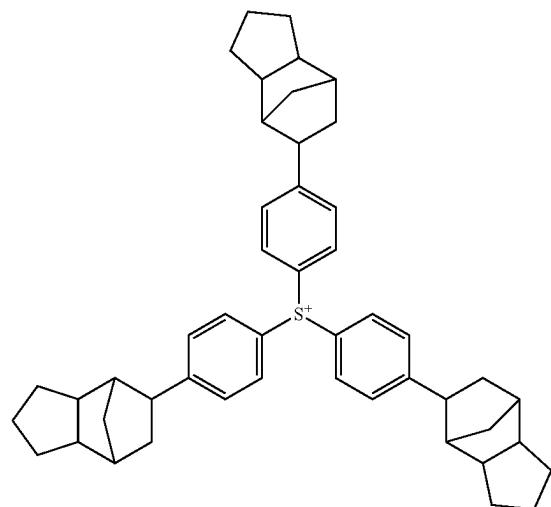
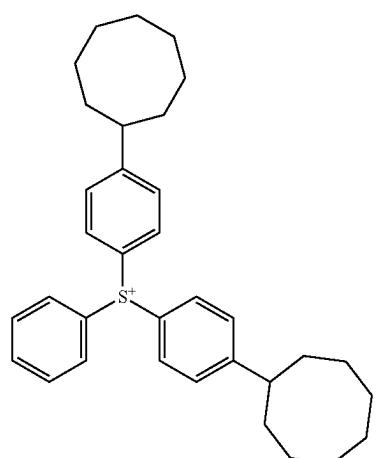
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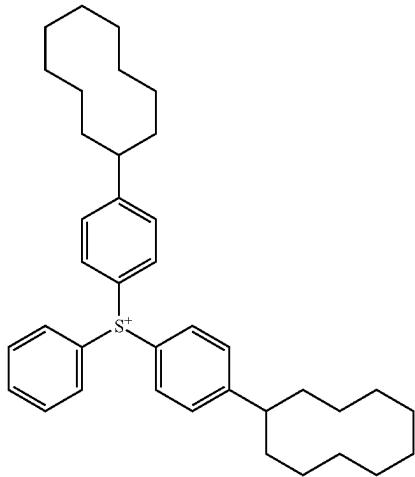
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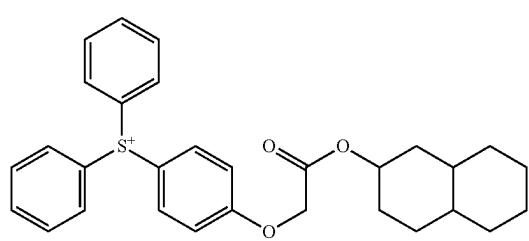
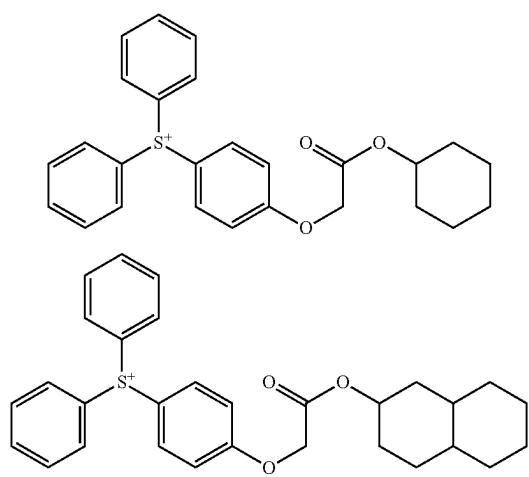
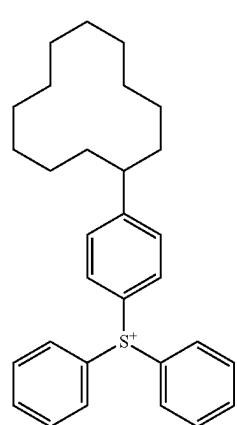
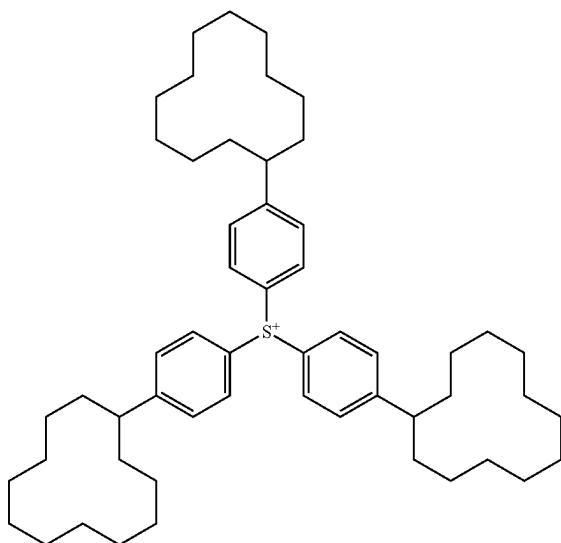
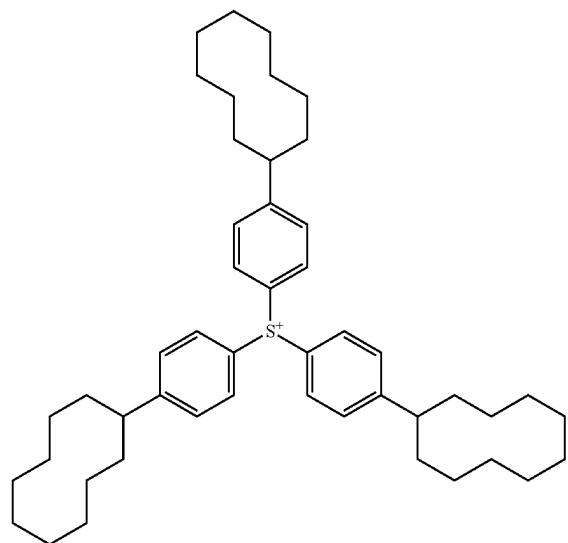
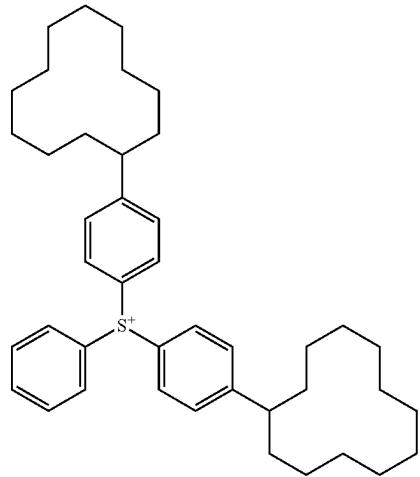
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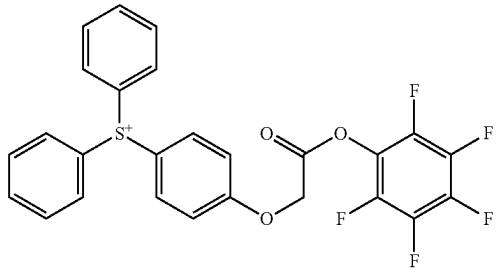
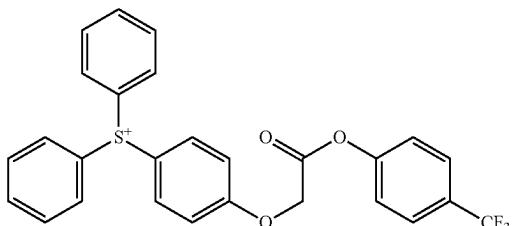
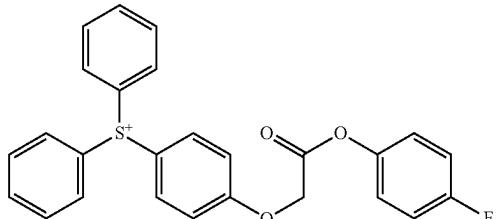
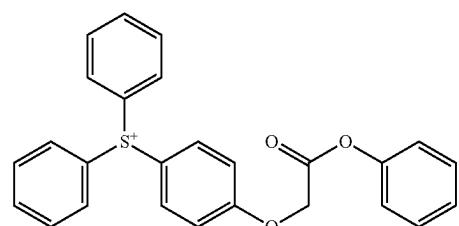
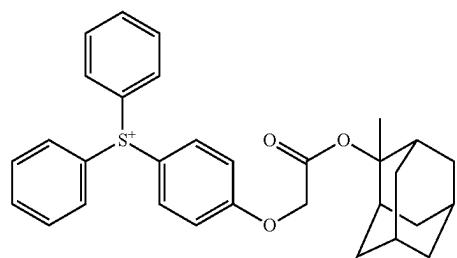
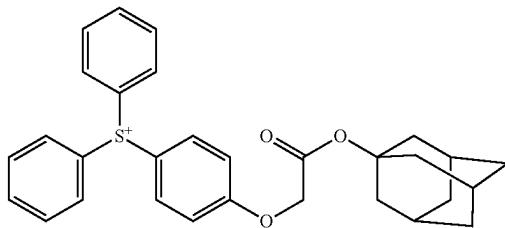
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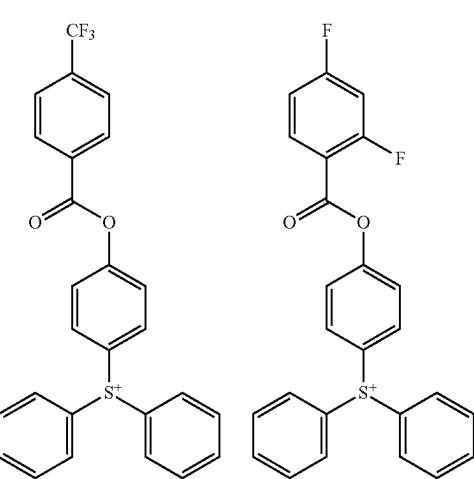
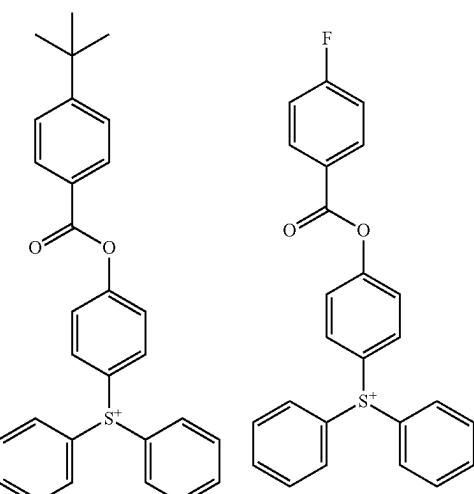
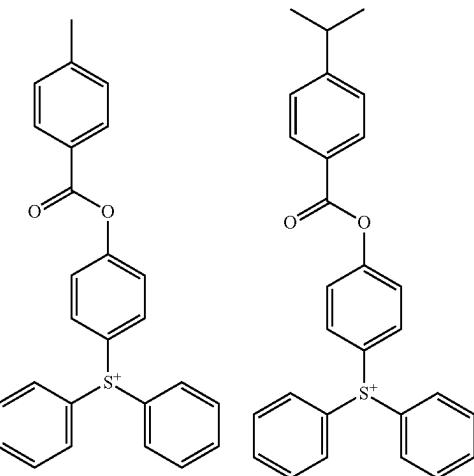
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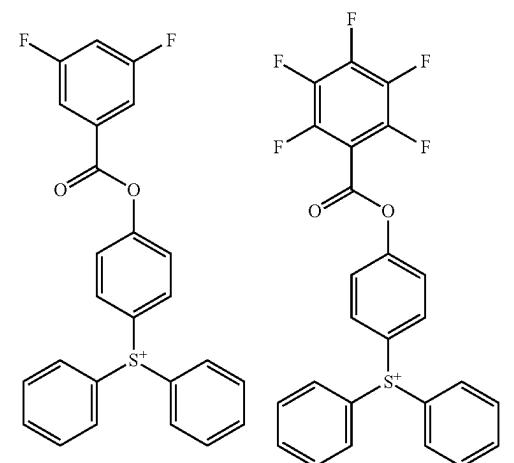
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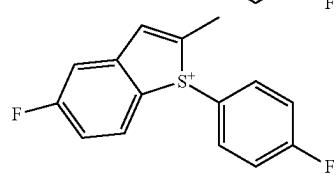
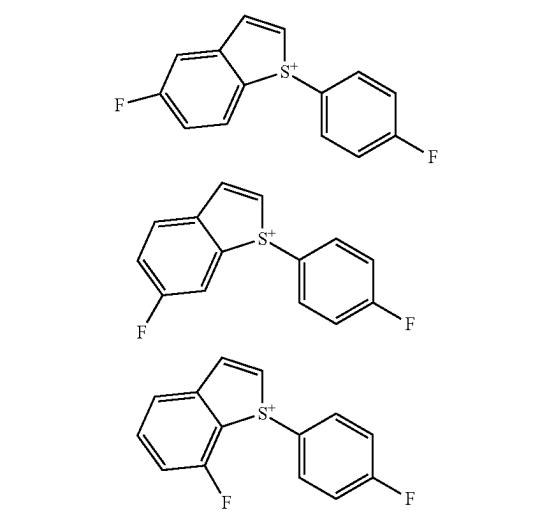
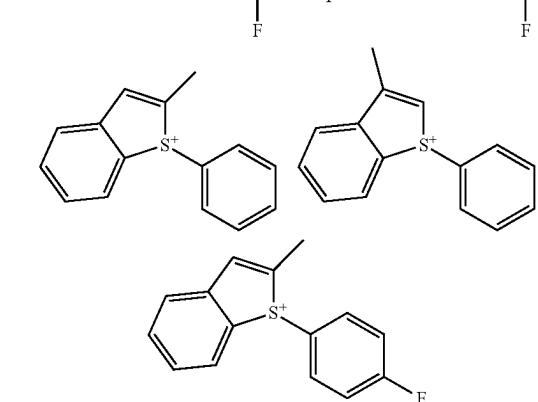
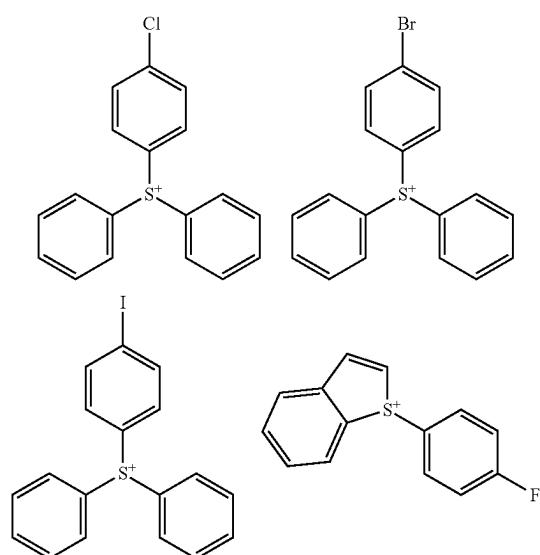
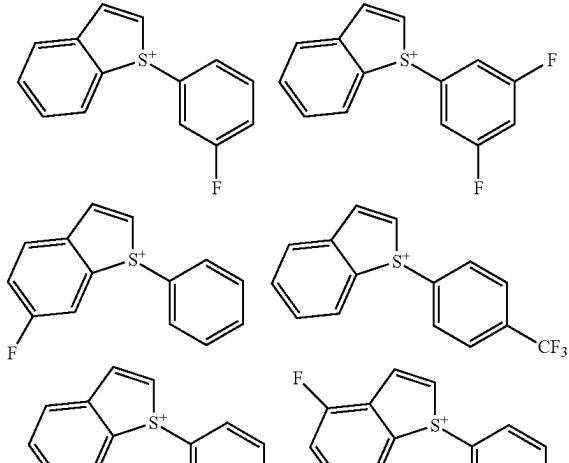
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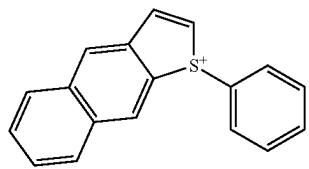
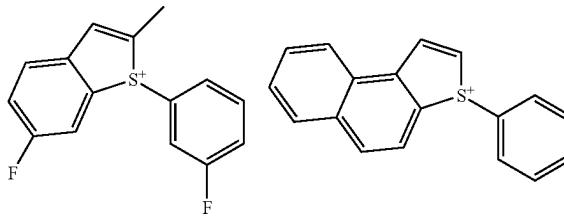
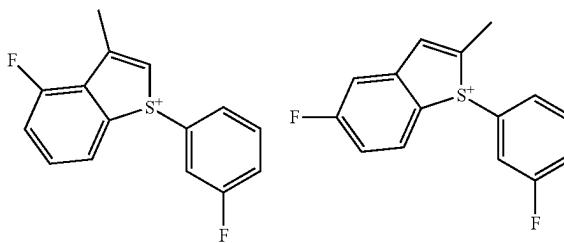
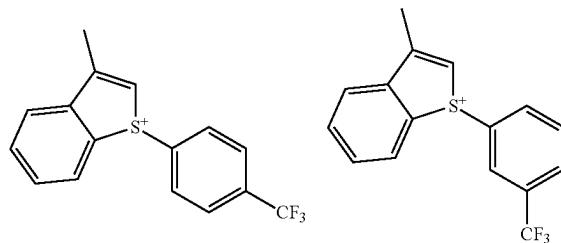
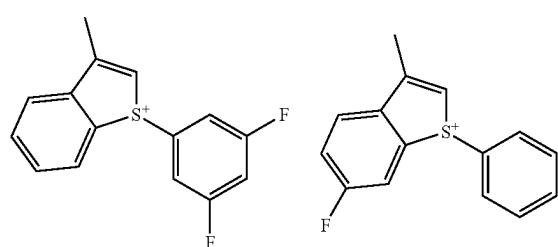
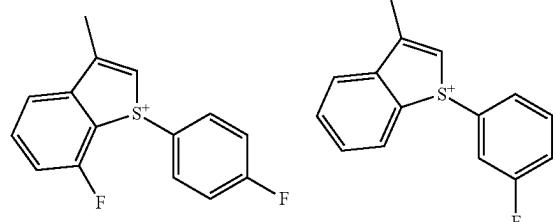
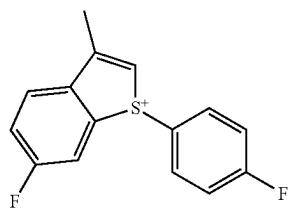
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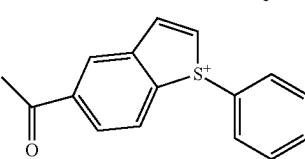
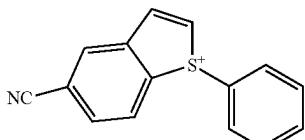
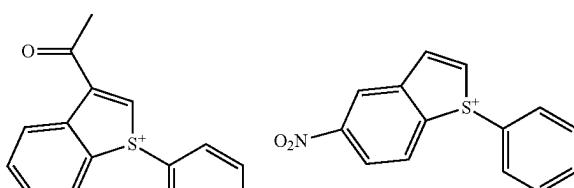
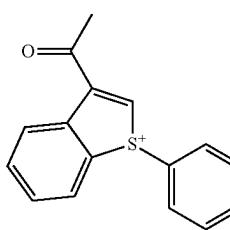
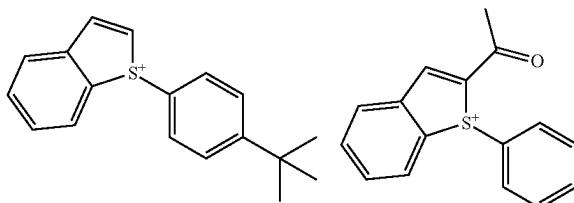
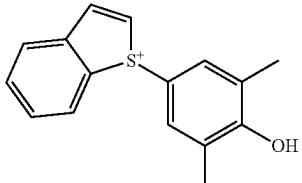
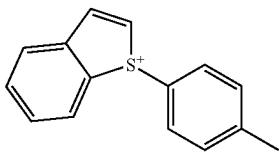
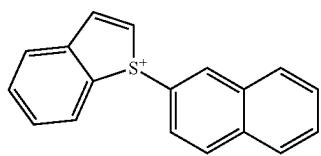
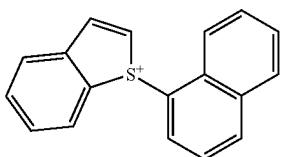
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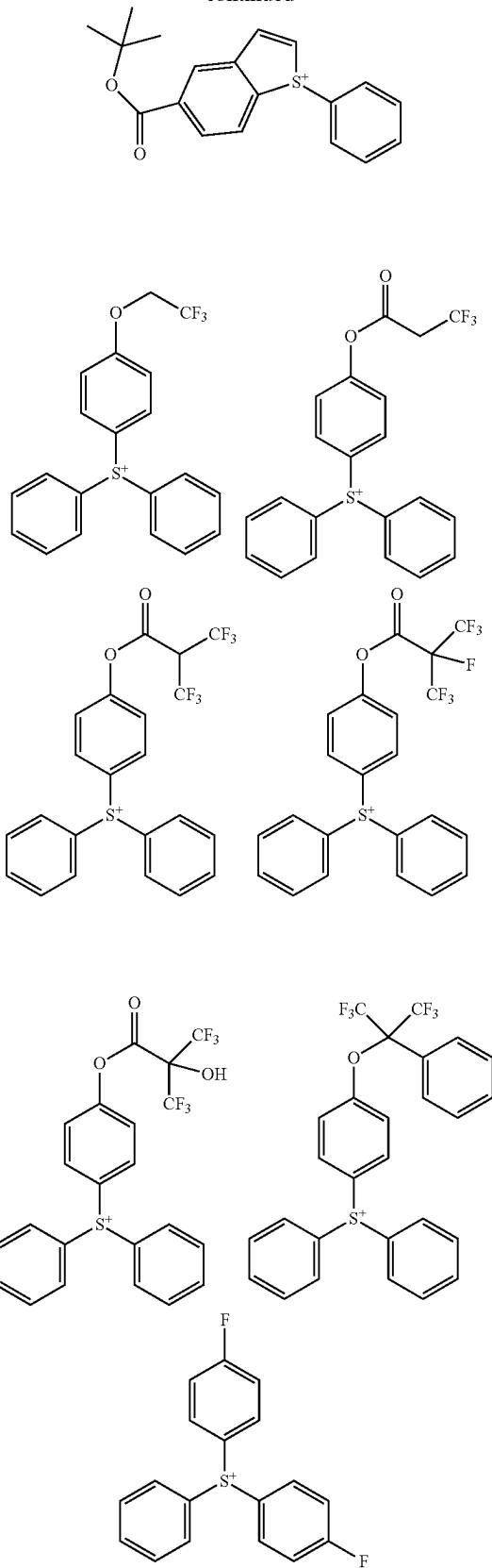
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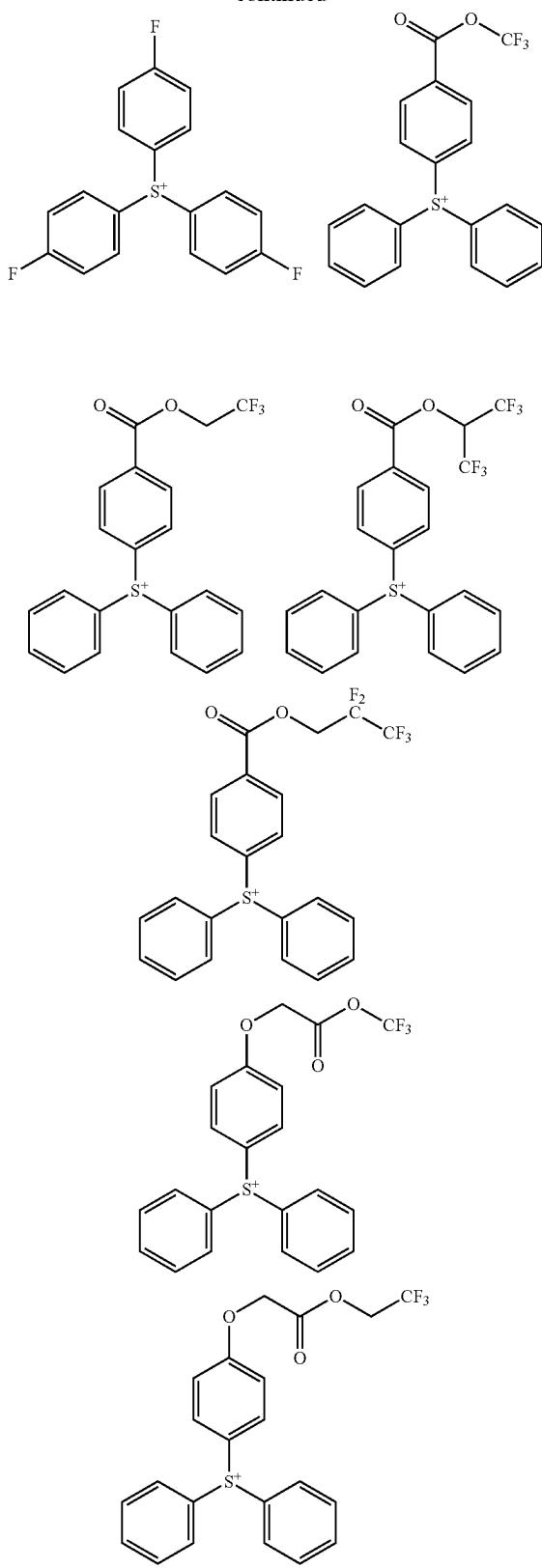
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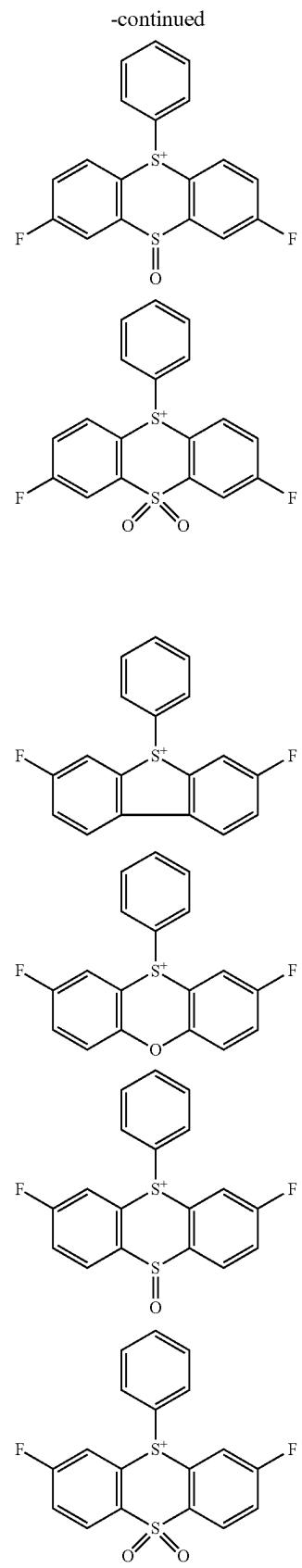
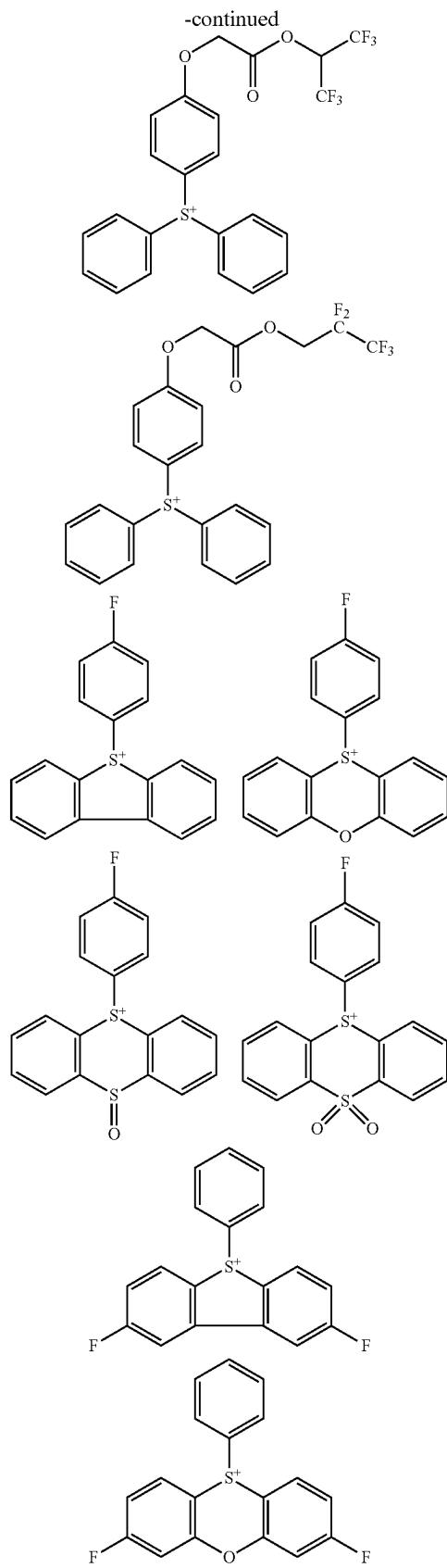


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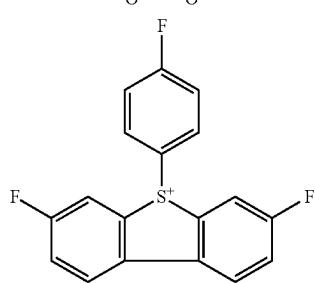
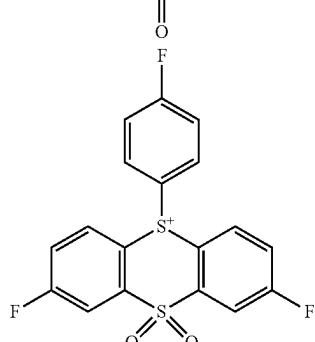
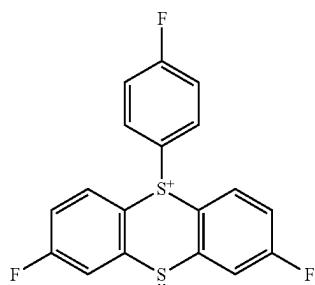
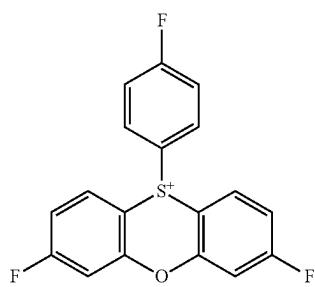
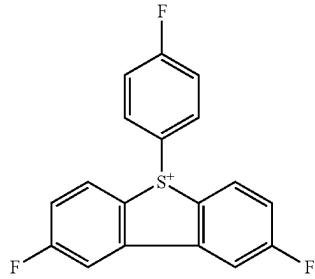


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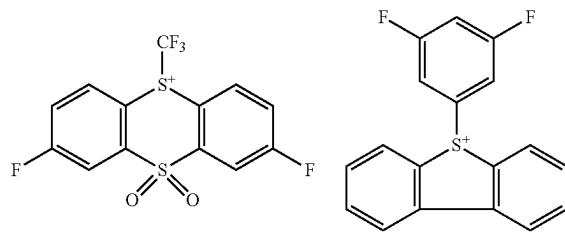
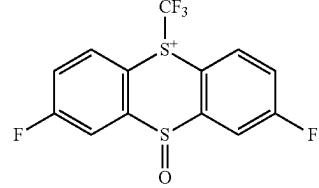
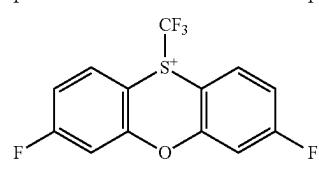
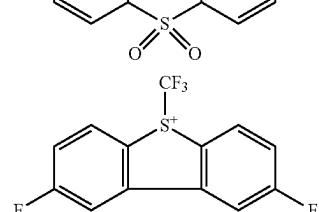
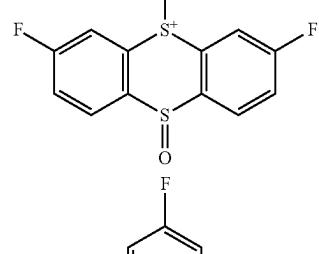
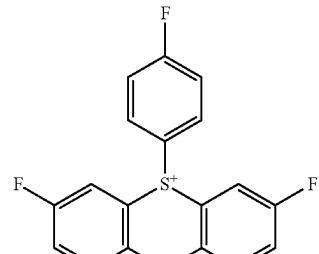




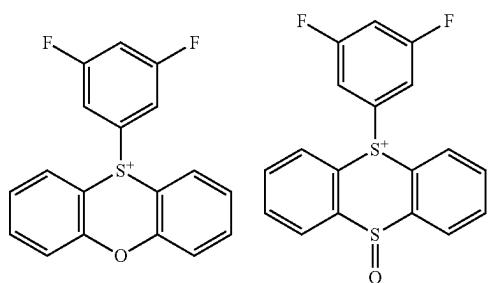
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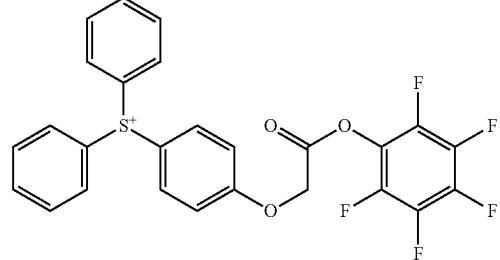
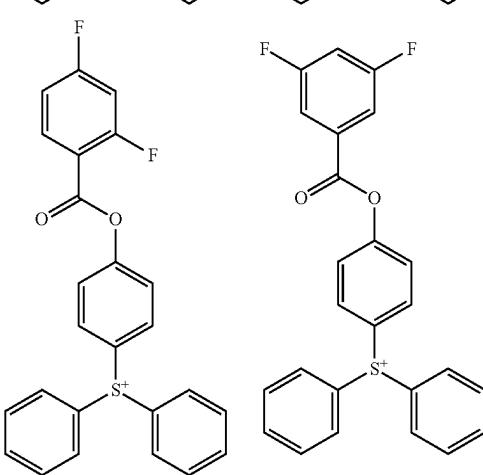
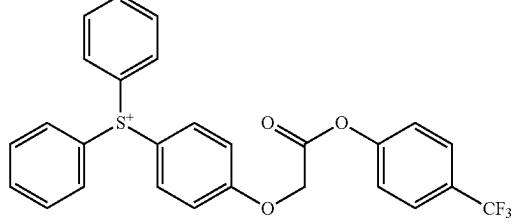
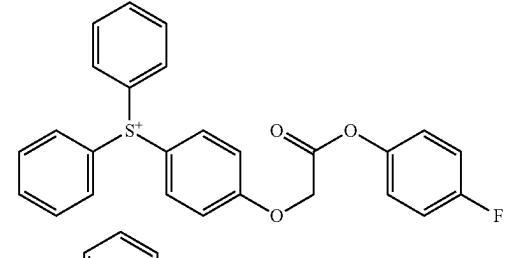
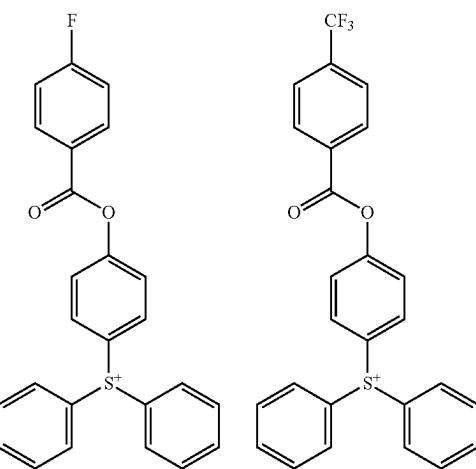
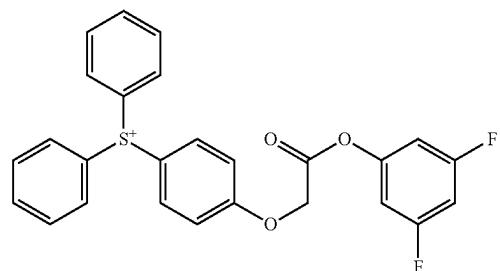
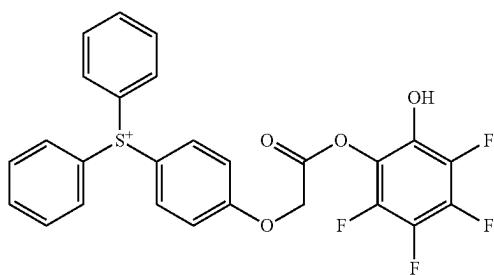
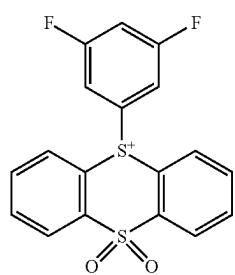
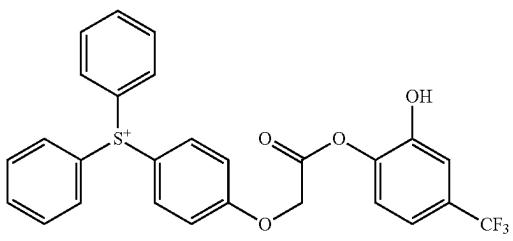
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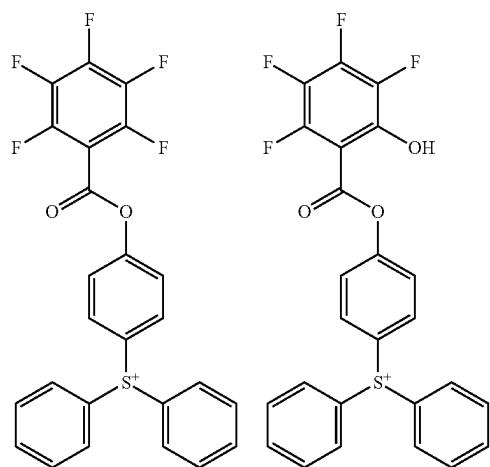
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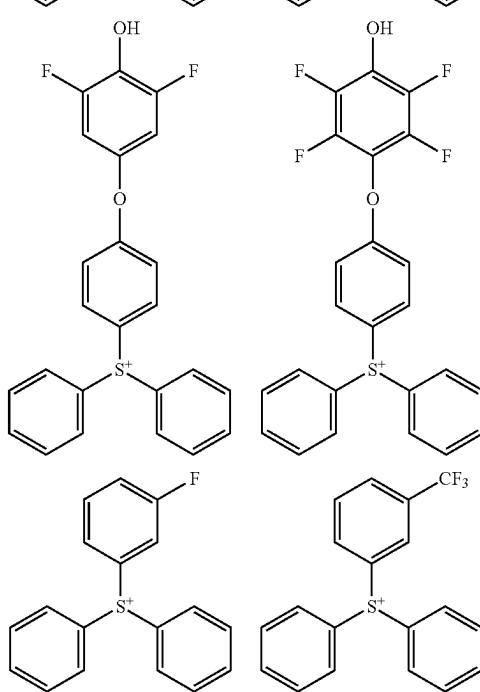
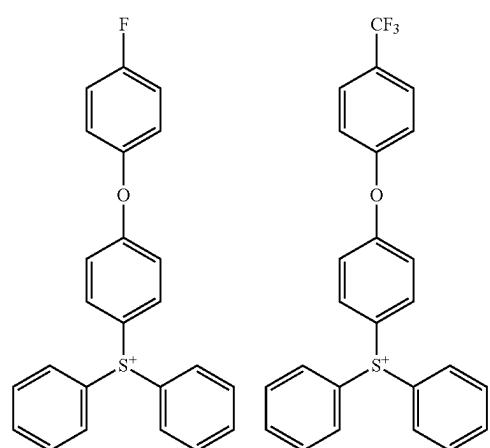
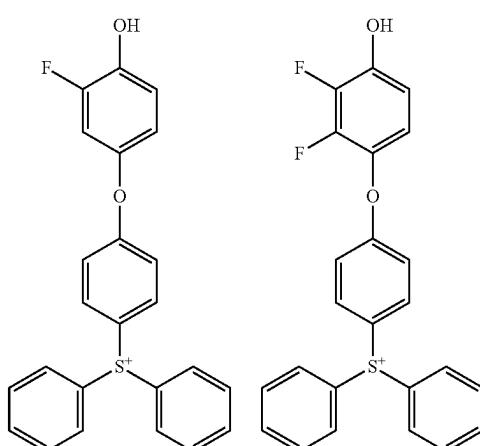
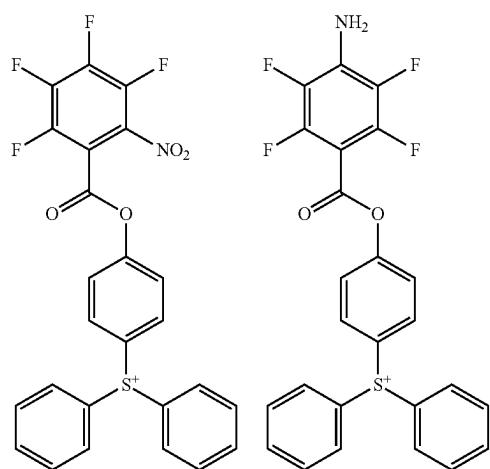
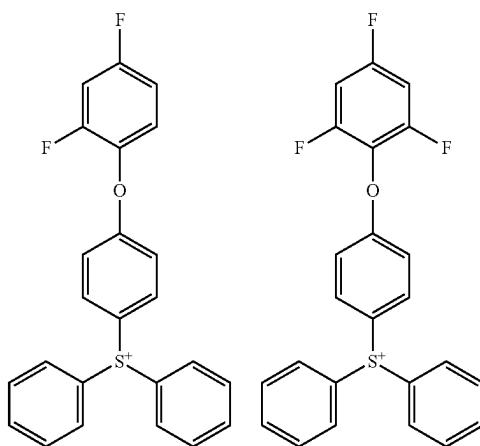
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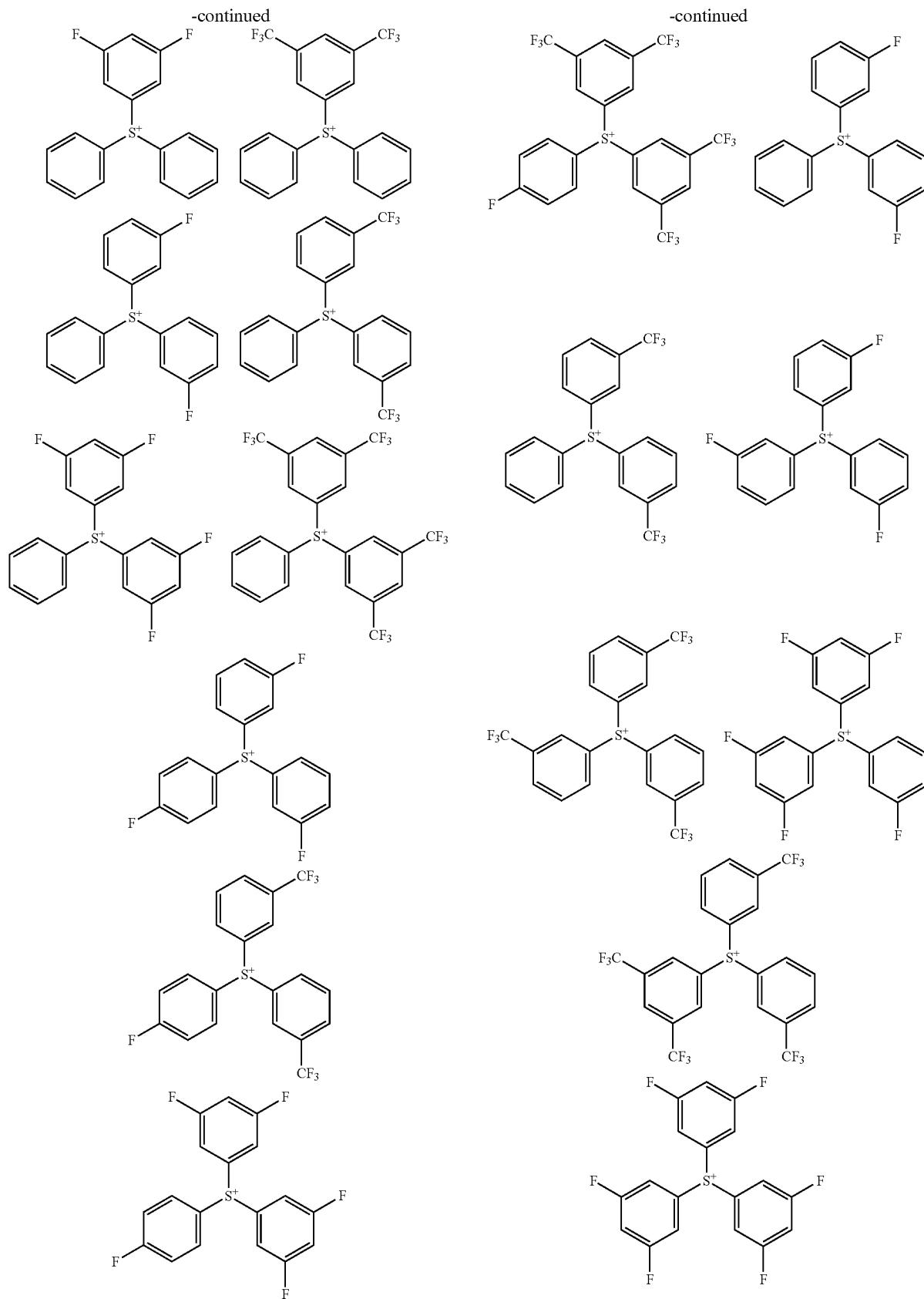


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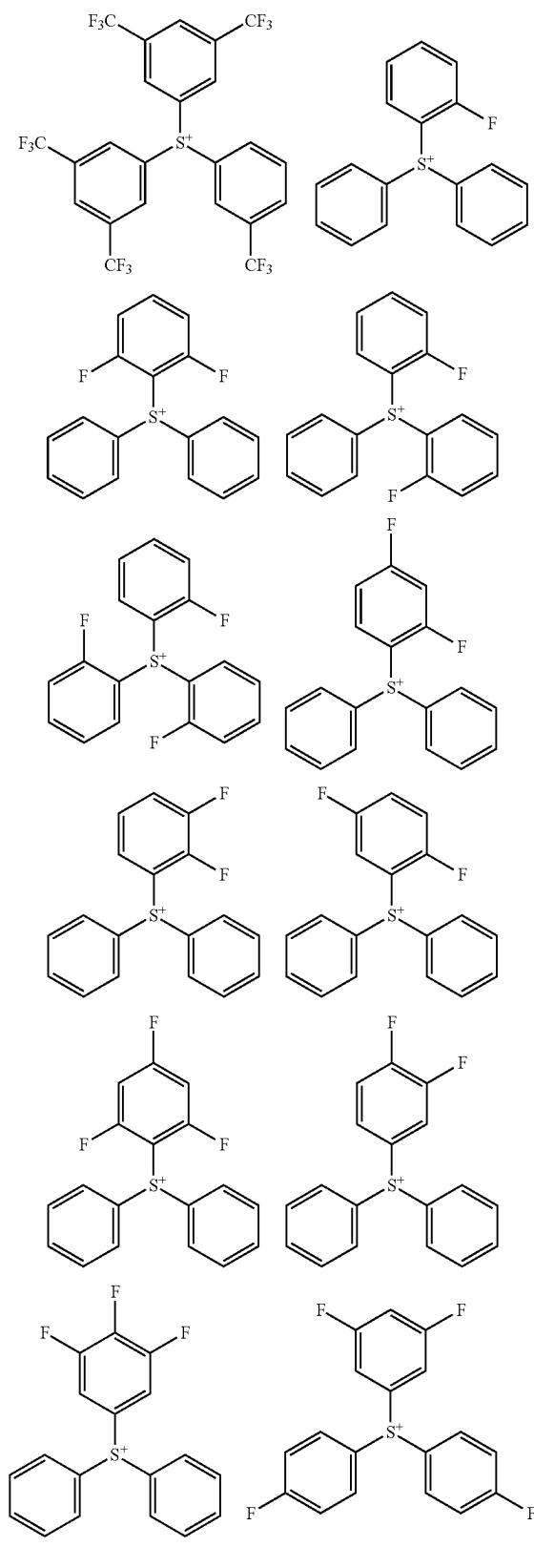


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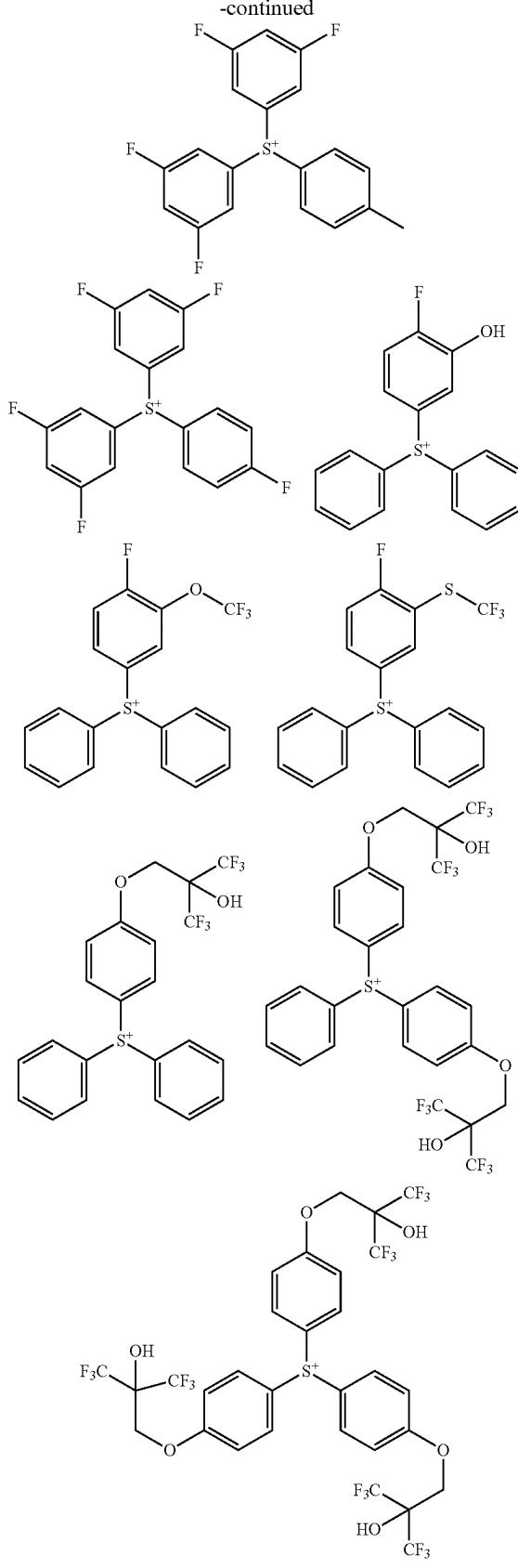




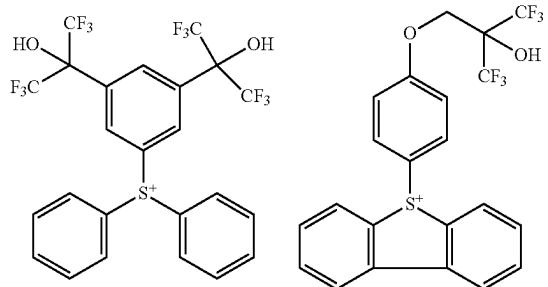
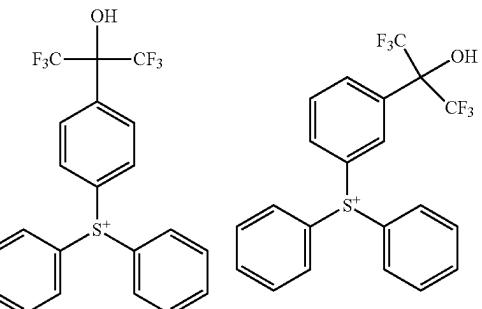
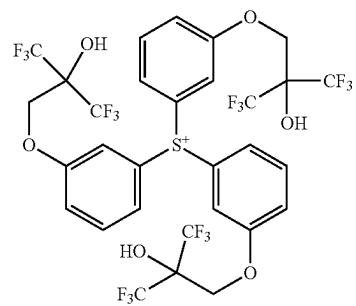
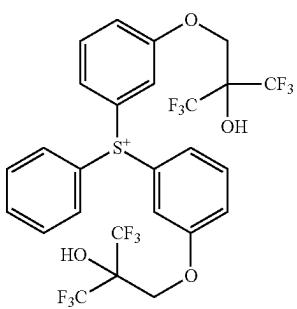
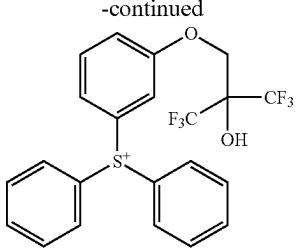
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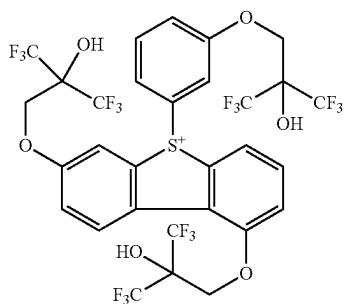
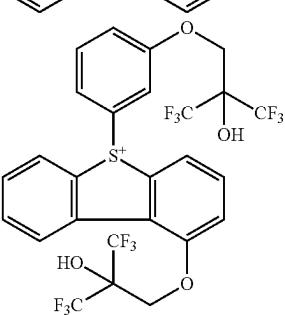
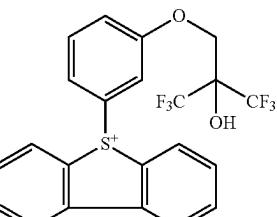
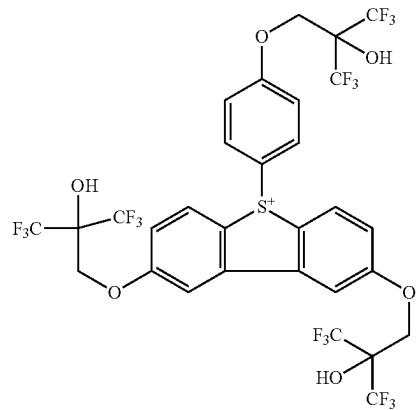
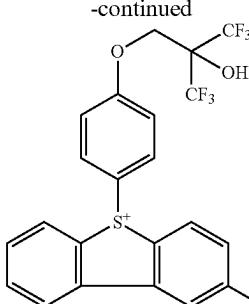
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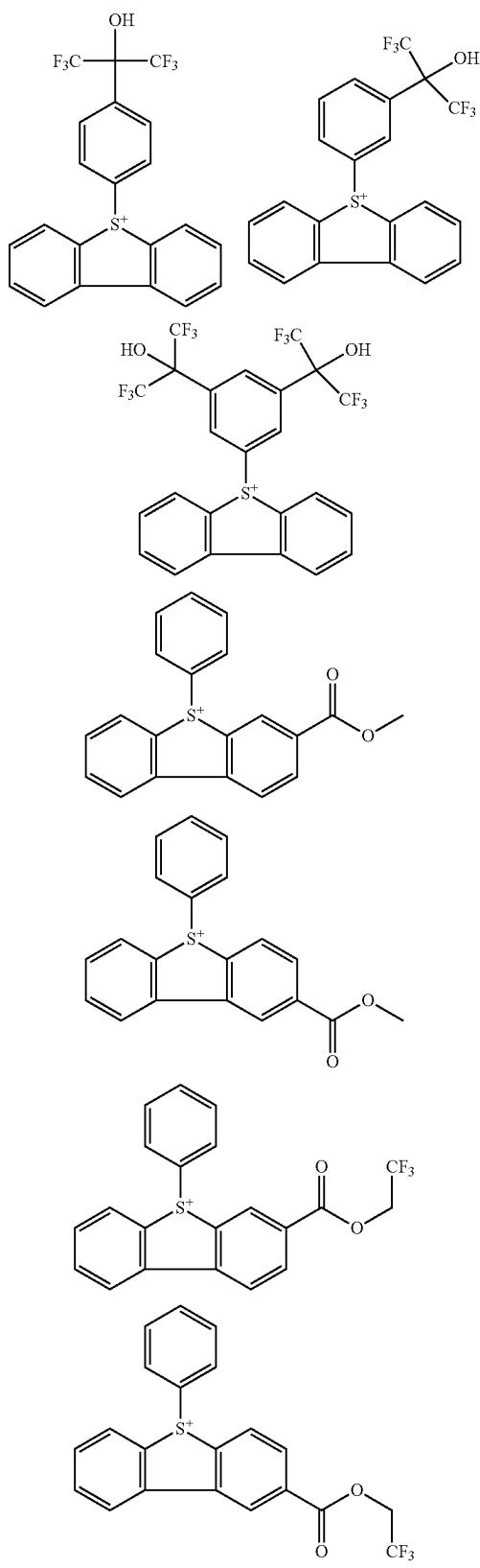
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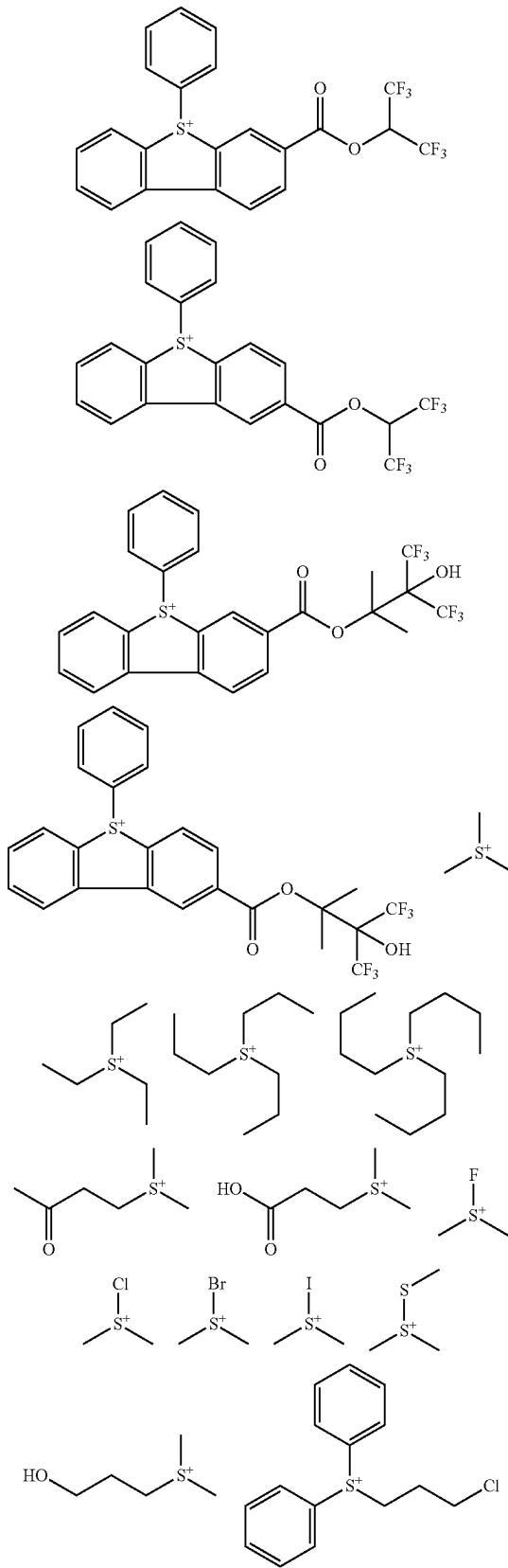
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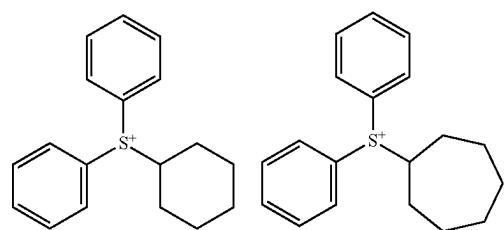
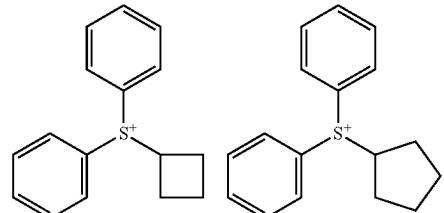
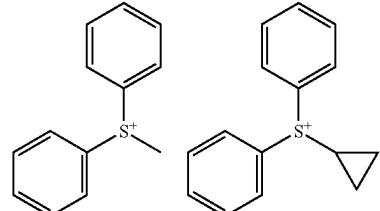
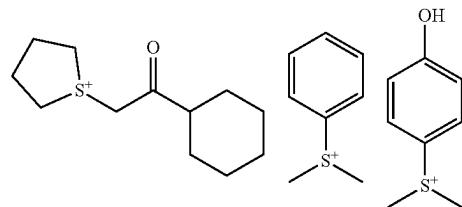
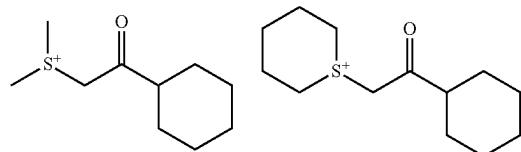
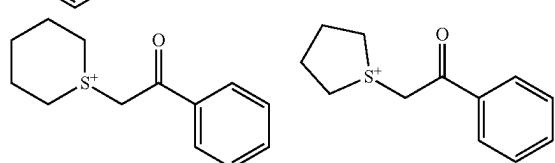
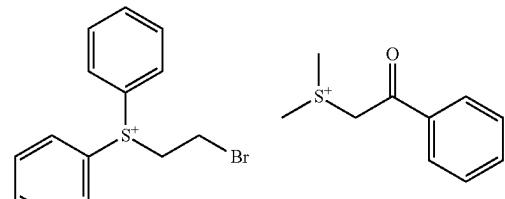
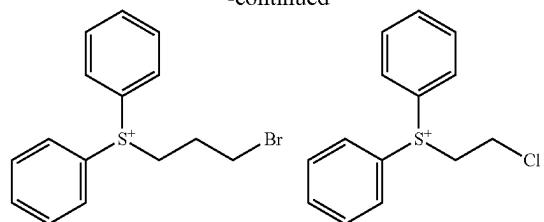
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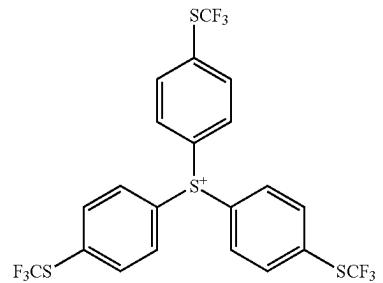
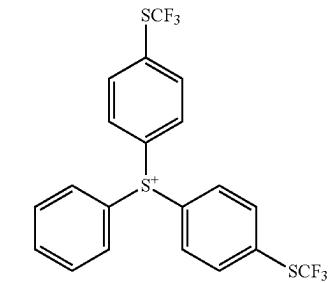
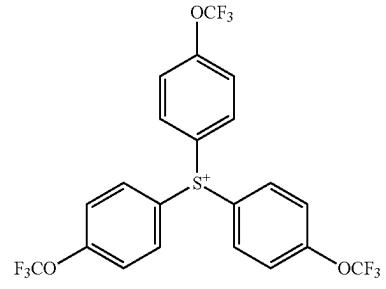
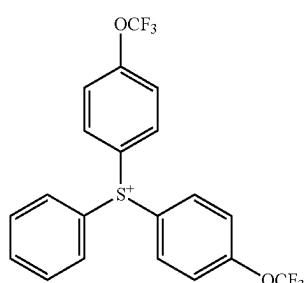
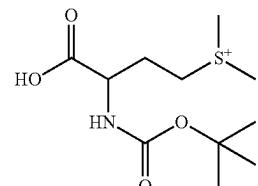
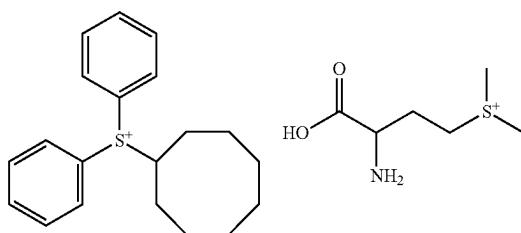
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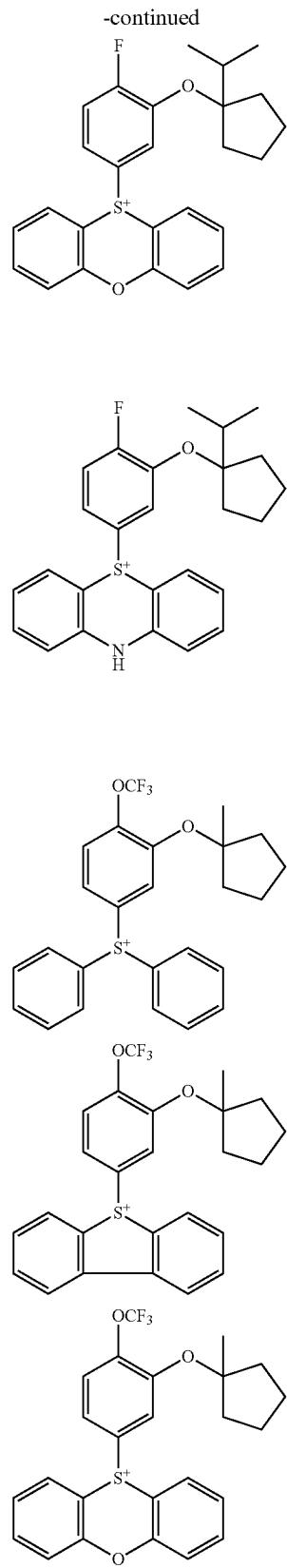
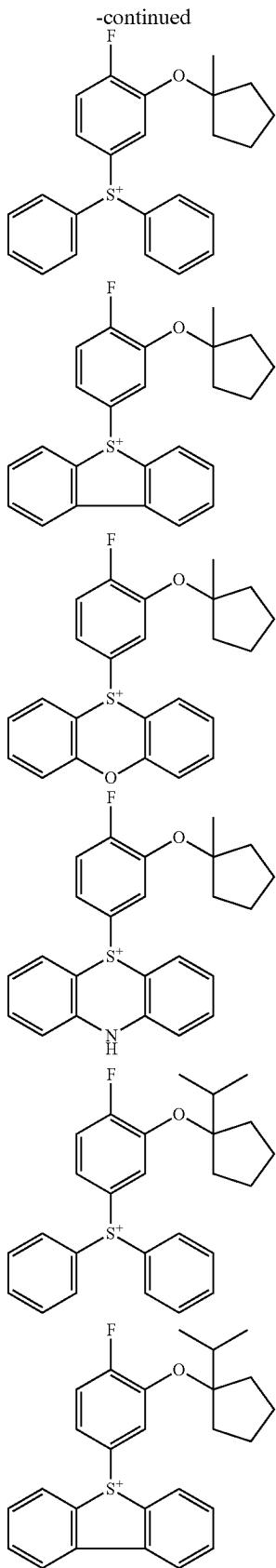


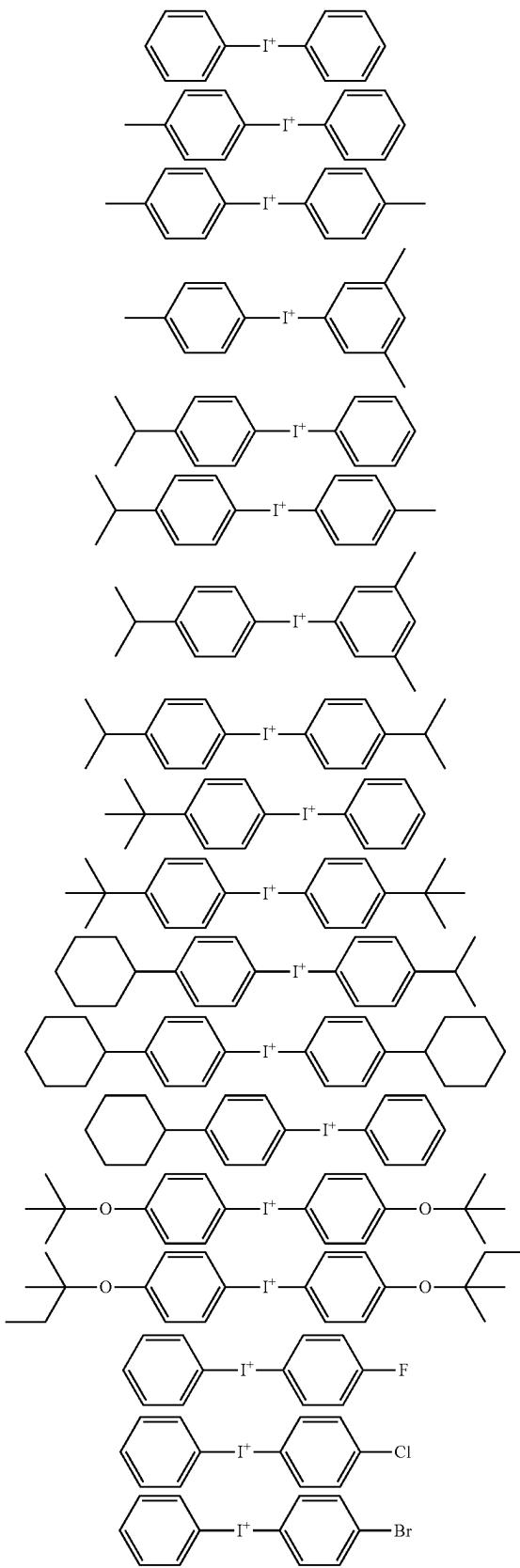
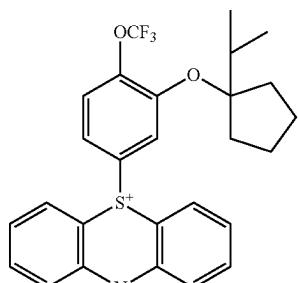
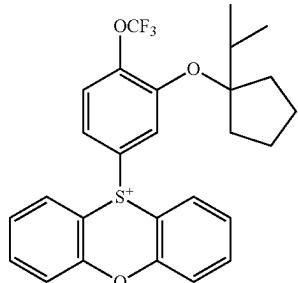
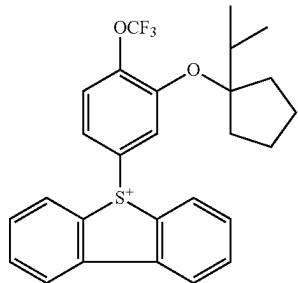
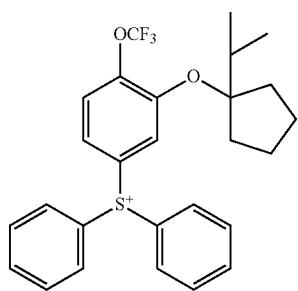
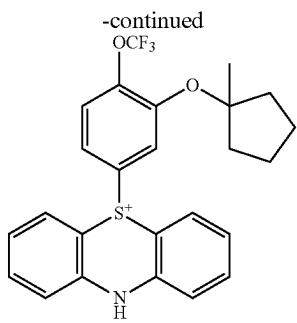
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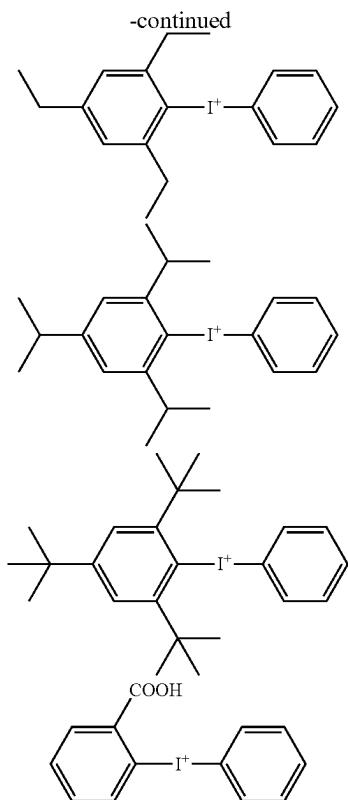
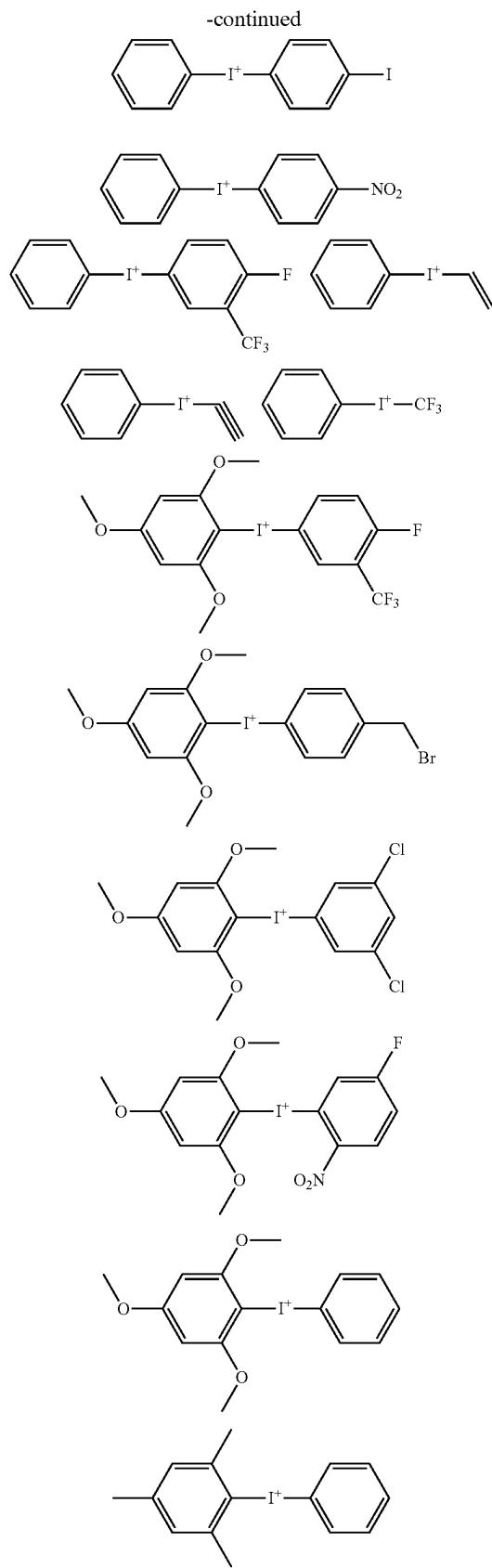
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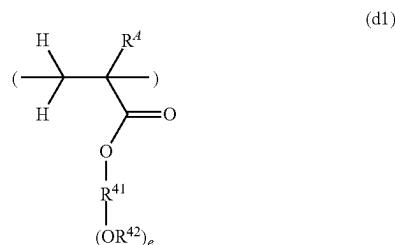
[0242] Examples of the iodonium cation having formula (cation-2) are shown below, but not limited thereto.



[0243] Exemplary structures of the repeat units (c1) to (c4) include arbitrary combinations of anions with cations, both as exemplified above.

[0244] Of the repeat units (c1) to (c4), repeat units (c2), (c3) and (c4) are preferred from the aspect of controlling acid diffusion. Repeat units (c2) and (c4) are more preferred from the aspect of the acid strength of generated acid. Repeat units (c2) are most preferred from the aspect of solvent solubility.

[0245] The base polymer may further comprise repeat units (d) of a structure having a hydroxy group protected with an acid labile group. The repeat unit (d) is not particularly limited as long as the unit includes one or more structures having a hydroxy group protected with a protective group such that the protective group is decomposed to generate the hydroxy group under the action of acid. Repeat units having the formula (d1) are preferred.



[0246] In formula (d1), R⁴ is as defined above. R⁴¹ is a C₁-C₃₀ (e+1)-valent hydrocarbon group which may contain a heteroatom. R⁴² is an acid labile group, and e is an integer of 1 to 4.

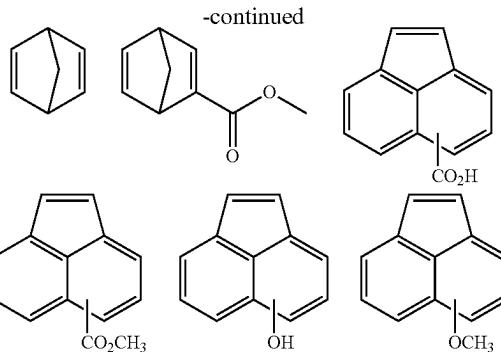
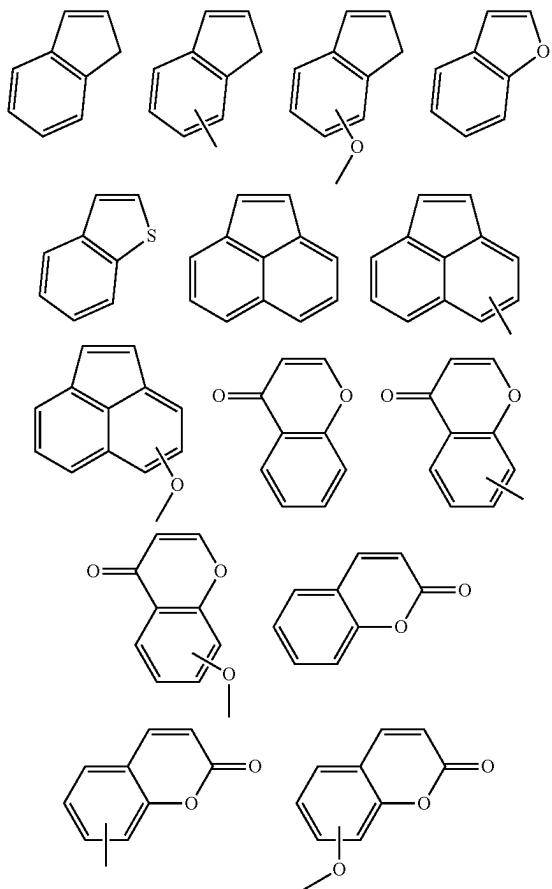
[0247] In formula (d1), the acid labile group R⁴² is deprotected under the action of acid so that a hydroxy group is generated. The structure of R⁴² is not particularly limited. An acetal structure, ketal structure, alkoxy carbonyl group and alkoxy methyl group having the following formula (d2) are preferred, with the alkoxy methyl group having formula (d2) being more preferred.



[0248] Herein R⁴³ is a C₁-C₁₅ hydrocarbyl group.

[0249] Illustrative examples of the acid labile group R⁴², the alkoxy methyl group having formula (d2), and the repeat units (d) are as exemplified for the repeat units (d) in JP-A 2020-111564 (US 20200223796).

[0250] In addition to the foregoing units, the base polymer may further comprise repeat units (e) derived from indene, benzofuran, benzothiophene, acenaphthylene, chromone, coumarin, norbornadiene and derivatives thereof. Examples of the monomer from which repeat units (e) are derived are shown below, but not limited thereto.



[0251] The base polymer may further comprise repeat units (f) derived from indane, vinylpyridine or vinylcarbazole.

[0252] In the polymer, repeat units (a1), (a2), (a3), (b1), (b2), (c1) to (c4), (d), (e), and (f) are incorporated in a ratio of preferably 0≤a1≤0.8, 0≤a2≤0.8, 0≤a3≤0.6, 0≤b1≤0.8, 0≤b2≤0.5, 0≤c1≤0.4, 0≤c2≤0.4, 0≤c3≤0.4, 0≤c4≤0.4, 0≤d≤0.3, 0≤e≤0.3, and 0≤f≤0.3; more preferably 0≤a1≤0.7, 0≤a2≤0.7, 0≤a3≤0.5, 0≤b1≤0.7, 0≤b2≤0.4, 0≤c1≤0.3, 0≤c2≤0.3, 0≤c3≤0.3, 0≤c4≤0.3, 0≤d≤0.2, 0≤e≤0.2, and 0≤f≤0.2. It is noted that a1+a2+a3+b1+b2+c1+c2+c3+c4+d+e+f≤1.0.

[0253] The polymer should preferably have a weight average molecular weight (Mw) in the range of 1,000 to 500,000, and more preferably 3,000 to 100,000, as measured by GPC versus polystyrene standards using tetrahydrofuran (THF) or N,N-dimethylformamide (DMF) solvent. A Mw in the range ensures that the resist film has etch resistance and eliminates the risk of resolution decline by a failure to provide a difference in dissolution rate before and after exposure.

[0254] The influence of Mw/Mn becomes stronger as the pattern rule becomes finer. Therefore, the polymer should preferably have a narrow dispersity (Mw/Mn) of 1.0 to 2.0 in order to provide a resist composition suitable for micropatterning to a small feature size. A Mw/Mn in the range ensures that the contents of lower and higher molecular weight polymer fractions are low and eliminates a possibility that foreign matter is left on the pattern or the pattern profile is degraded.

[0255] The polymer may be synthesized, for example, by dissolving a monomer or monomers corresponding to the above-mentioned repeat units in an organic solvent, adding a radical polymerization initiator, and heating for polymerization.

[0256] Examples of the organic solvent which can be used for polymerization include toluene, benzene, THF, diethyl ether, dioxane, cyclohexane, cyclopentane, methyl ethyl ketone (MEK), propylene glycol monomethyl ether acetate (PGMEA), and γ-butyrolactone (GBL). Examples of the polymerization initiator used herein include 2,2'-azobisisobutyronitrile (AIBN), 2,2'-azobis(2,4-dimethylvaleronitrile), dimethyl 2,2-azobis(2-methylpropionate), 1,1'-azobis(1-acetoxy-1-phenylethane), benzoyl peroxide, and lauroyl peroxide. The initiator is preferably added in an amount of 0.01 to 25 mol % based on the total of monomers to be polymerized. The reaction temperature is preferably 50 to 150° C., more preferably 60 to 100° C. The reaction time is preferably 2 to 24 hours, more preferably 2 to 12 hours in view of production efficiency.

[0257] The polymerization initiator may be fed to the reactor either by adding the initiator to the monomer solution and feeding the solution to the reactor, or by dissolving the initiator in a solvent to form an initiator solution and feeding the initiator solution and the monomer solution independently to the reactor. Because of a possibility that in the standby duration, the initiator generates a radical which triggers polymerization reaction to form a ultra-high-molecular-weight polymer, it is preferred from the standpoint of quality control to prepare the monomer solution and the initiator solution separately and add them dropwise. The acid labile group that has been incorporated in the monomer may be kept as such, or polymerization may be followed by protection or partial protection. During the polymer synthesis, any known chain transfer agent such as dodecyl mercaptan or 2-mercaptoethanol may be added for molecular weight control purpose. The amount of chain transfer agent added is preferably 0.01 to 20 mol % based on the total of monomers.

[0258] When a hydroxy-containing monomer is copolymerized, the hydroxy group is substituted by an acetal group which is susceptible to deprotection with acid, typically ethoxyethoxy, prior to polymerization, and the polymerization is followed by deprotection with weak acid and water. Alternatively, the hydroxy group is substituted by an acetyl, formyl or pivaloyl group prior to polymerization, and the polymerization is followed by alkaline hydrolysis.

[0259] When hydroxystyrene or hydroxyvinylnaphthalene is copolymerized, one method is dissolving hydroxystyrene or hydroxyvinylnaphthalene and other monomers in an organic solvent, adding a radical polymerization initiator thereto, and heating the solution for polymerization. In an alternative method, acetoxystyrene or acetoxyvinylnaphthalene is used instead, and after polymerization, the acetoxy group is deprotected by alkaline hydrolysis, for thereby converting the polymer product to polyhydroxystyrene or polyhydroxyvinylnaphthalene.

[0260] For alkaline hydrolysis, a base such as aqueous ammonia or triethylamine may be used. Preferably the reaction temperature is -20° C. to 100° C., more preferably 0° C. to 60° C., and the reaction time is 0.2 to 100 hours, more preferably 0.5 to 20 hours.

[0261] The amounts of monomers in the monomer solution may be determined appropriate so as to provide the preferred fractions of repeat units.

[0262] It is now described how to use the polymer obtained by the above preparation method. The reaction solution resulting from polymerization reaction may be used as the final product. Alternatively, the polymer may be recovered in powder form through a purifying step such as re-precipitation step of adding the polymerization solution to a poor solvent and letting the polymer precipitate as powder, after which the polymer powder is used as the final product. It is preferred from the standpoints of operation efficiency and consistent quality to handle a polymer solution which is obtained by dissolving the powder polymer resulting from the purifying step in a solvent, as the final product.

[0263] The solvents which can be used herein are described in JP-A 2008-111103, paragraphs [0144]-[0145] (U.S. Pat. No. 7,537,880). Exemplary solvents include ketones such as cyclohexanone and methyl-2-n-pentyl ketone; alcohols such as 3-methoxybutanol, 3-methyl-3-methoxybutanol, 1-methoxy-2-propanol, and 1-ethoxy-2-propanol; keto-alcohols such as diacetone alcohol (DAA); ethers such as propylene glycol monomethyl ether (PGME), ethylene glycol monomethyl ether, propylene glycol monoethyl ether, propylene glycol dimethyl ether, and diethylene glycol dimethyl ether; esters such as propylene glycol monomethyl ether acetate (PGMEA), propylene glycol monoethyl ether acetate, ethyl lactate, ethyl pyruvate, butyl acetate, methyl 3-methoxypropionate, ethyl 3-ethoxypropionate, tert-butyl acetate, tert-butyl propionate, and propylene glycol mono-tert-butyl ether acetate; lactones such as γ-butyrolactone (GBL); and high-boiling alcohols such as diethylene glycol, propylene glycol, glycerol, 1,4-butanediol, and 1,3-butanediol, which may be used alone or in admixture.

ethers such as propylene glycol monomethyl ether (PGME), ethylene glycol monomethyl ether, propylene glycol monoethyl ether, ethylene glycol monoethyl ether, propylene glycol dimethyl ether, and diethylene glycol dimethyl ether; esters such as propylene glycol monomethyl ether acetate (PGMEA), propylene glycol monoethyl ether acetate, ethyl lactate, ethyl pyruvate, butyl acetate, methyl 3-methoxypropionate, ethyl 3-ethoxypropionate, tert-butyl acetate, tert-butyl propionate, and propylene glycol mono-tert-butyl ether acetate; lactones such as γ-butyrolactone (GBL); and high-boiling alcohols such as diethylene glycol, propylene glycol, glycerol, 1,4-butanediol, and 1,3-butanediol, which may be used alone or in admixture.

[0264] The polymer solution preferably has a polymer concentration of 0.01 to 30% by weight, more preferably 0.1 to 20% by weight.

[0265] Prior to use, the reaction solution or polymer solution is preferably filtered through a filter. Filtration is effective for consistent quality because foreign particles and gel which can cause defects are removed.

[0266] Suitable materials of which the filter is made include fluorocarbon, cellulose, nylon, polyester, and hydrocarbon base materials. Preferred for the filtration of a resist composition are filters made of fluorocarbons commonly known as Teflon®, hydrocarbons such as polyethylene and polypropylene, and nylon. While the pore size of the filter may be selected appropriate to comply with the desired cleanliness, the filter preferably has a pore size of up to 100 nm, more preferably up to 20 nm. A single filter may be used or a plurality of filters may be used in combination. Although the filtering method may be single pass of the solution, preferably the filtering step is repeated by flowing the solution in a circulating manner. In the polymer preparation process, the filtering step may be carried out any times, in any order and in any stage. The reaction solution as polymerized or the polymer solution may be filtered, preferably both are filtered.

[0267] The base polymer (B) may be used alone or as a blend of two or more polymers which differ in compositional ratio, Mw and/or Mw/Mn. Component (B) may also be a blend of the base polymer defined above and a hydrogenated product of ROMP. For the ROMP, reference is made to JP-A 2003-066612.

(C) Organic Solvent

[0268] The resist composition may comprise an organic solvent as component (C). The organic solvent (C) is not particularly limited as long as the foregoing and other components are soluble therein. Suitable solvents include ketones such as cyclopentanone, cyclohexanone, and methyl-2-n-pentyl ketone; alcohols such as 3-methoxybutanol, 3-methyl-3-methoxybutanol, 1-methoxy-2-propanol, and 1-ethoxy-2-propanol; keto-alcohols such as diacetone alcohol (DAA); ethers such as propylene glycol monomethyl ether (PGME), ethylene glycol monomethyl ether, propylene glycol monoethyl ether, propylene glycol dimethyl ether, and diethylene glycol dimethyl ether; esters such as propylene glycol monomethyl ether acetate (PGMEA), propylene glycol monoethyl ether acetate, ethyl lactate, ethyl pyruvate, butyl acetate, methyl 3-methoxypropionate, ethyl 3-ethoxypropionate, tert-butyl acetate, tert-butyl propionate, and propylene glycol mono-tert-butyl ether acetate; and lactones such as γ-butyrolactone (GBL), and mixtures thereof.

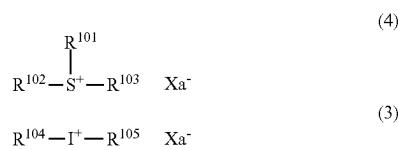
[0269] Of the foregoing organic solvents, it is recommended to use 1-ethoxy-2-propanol, PGMEA, cyclohexanone, GBL, DAA and mixtures thereof because the base polymer (B) is most soluble therein.

[0270] The organic solvent (C) is preferably added in an amount of 200 to 5,000 parts by weight, and more preferably 400 to 3,500 parts by weight per 80 parts by weight of the base polymer (B). The organic solvent may be used alone or in admixture.

(D) Photoacid Generator

[0271] The chemically amplified resist composition may comprise (D) a photoacid generator. The PAG is not particularly limited as long as it is capable of generating an acid having a higher acid strength than the sulfonic acid generated by the quencher or onium salt (A), upon exposure to high-energy radiation.

[0272] The preferred PAG is a salt having the formula (2) or (3).

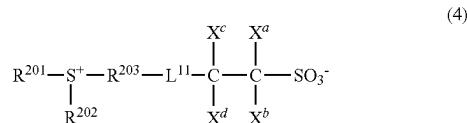


[0273] In formula (2), R¹⁰¹ to R¹⁰⁵ are each independently a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom. Any two of R¹⁰¹, R¹⁰² and R¹⁰³ may bond together to form a ring with the sulfur atom to which they are attached. Examples of the hydrocarbyl group are as exemplified above for R^{c1} to R^{c5} in formulae (cation-1) and (cation-2).

[0274] Examples of the sulfonium cation in the salt having formula (2) are as exemplified above for the sulfonium cation having formula (cation-1). Examples of the iodonium cation in the salt having formula (3) are as exemplified above for the iodonium cation having formula (cation-2).

[0275] In formulae (2) and (3), Xa⁻ is an anion of strong acid selected from formulae (c1-1) to (c1-5).

[0276] Compounds having the formula (4) are also preferred as the PAG (D).



[0277] In formula (4), R²⁰¹ and R²⁰² are each independently a C₁-C₃₀ hydrocarbyl group which may contain a heteroatom. R²⁰³ is a C₁-C₃₀ hydrocarbylene group which may contain a heteroatom. Any two of R²⁰¹, R²⁰² and R²⁰³ may bond together to form a ring with the sulfur atom to which they are attached.

[0278] The C₁-C₃₀ hydrocarbyl group represented by R²⁰¹ and R²⁰² may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C₁-C₃₀ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, tert-pentyl, n-hexyl, n-octyl, 2-ethylhexyl, n-nonyl, and n-decyl; C₃-C₃₀ cyclic

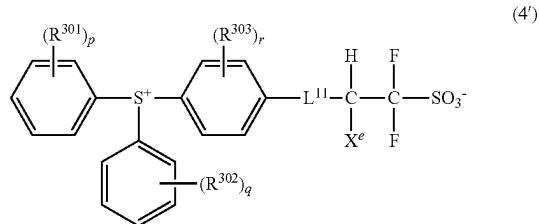
saturated hydrocarbyl groups such as cyclopentyl, cyclohexyl, cyclopentylmethyl, cyclopentylethyl, cyclopentylbutyl, cyclohexylmethyl, cyclohexylethyl, cyclohexylbutyl, norbornyl, oxanorbornyl, tricyclo[5.2.1.0^{2,6}]decyl, and adamantyl; and C₆-C₃₀ aryl groups such as phenyl, methylphenyl, ethylphenyl, n-propylphenyl, isopropylphenyl, n-butylphenyl, isobutylphenyl, sec-butylphenyl, tert-butylphenyl, naphthyl, methylnaphthyl, ethylnaphthyl, n-propylnaphthyl, isopropylnaphthyl, n-butylnaphthyl, isobutylnaphthyl, sec-butylnaphthyl, tert-butylnaphthyl, and anthracenyl, and combinations thereof. In these hydrocarbyl groups, some or all of the hydrogen atoms may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some constituent —CH₂— may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, cyano, fluorine, chlorine, bromine, iodine, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (—C(=O)—O—C(=O)—) or haloalkyl moiety.

[0279] The C₁-C₃₀ hydrocarbylene group R²⁰³ may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include C₁-C₃₀ alkanediyl groups such as methanediyl, ethane-1,1-diyl, ethane-1,2-diyl, propane-1,3-diyl, butane-1,4-diyl, pentane-1,5-diyl, hexane-1,6-diyl, heptane-1,7-diyl, octane-1,8-diyl, nonane-1,9-diyl, decane-1,10-diyl, undecane-1,11-diyl, dodecane-1,12-diyl, tridecane-1,13-diyl, tetradecane-1,14-diyl, pentadecane-1,15-diyl, hexadecane-1,16-diyl, and heptadecane-1,17-diyl; C₃-C₃₀ cyclic saturated hydrocarbylene groups such as cyclopantanediyl, cyclohexanediyl, norbornanediyl and adamantanediylyl; and arylene groups such as phenylene, methylphenylene, ethylphenylene, n-propylphenylene, isopropylphenylene, n-butylphenylene, isobutylphenylene, sec-butylphenylene, tert-butylphenylene, naphthylene, methylnaphthylene, ethylnaphthylene, n-propylnaphthylene, isopropylnaphthylene, n-butylnaphthylene, isobutylnaphthylene, sec-butylnaphthylene, and tert-butylnaphthylene. In these hydrocarbylene groups, some or all of the hydrogen atoms may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, or some constituent —CH₂— may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy, cyano, fluorine, chlorine, bromine, iodine, carbonyl, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride (—C(=O)—O—C(=O)—) or haloalkyl moiety. Of the heteroatoms, oxygen is preferred.

[0280] In formula (4), L¹¹ is a single bond, ether bond or a C₁-C₂₀ hydrocarbylene group which may contain a heteroatom. The hydrocarbylene group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for the hydrocarbylene group R²⁰³.

[0281] In formula (4), X^a, X^b, X^c and X^d are each independently hydrogen, fluorine or trifluoromethyl, at least one of X^a, X^b, X^c and X^d being fluorine or trifluoromethyl.

[0282] Of the PAGs having formula (4), those having formula (4') are preferred.



[0283] In formula (4'), L^{11} is as defined above. X^e is hydrogen or trifluoromethyl, preferably trifluoromethyl. R^{301} , R^{302} and R^{303} are each independently hydrogen or a $\text{C}_1\text{-C}_{20}$ hydrocarbyl group which may contain a heteroatom. The hydrocarbyl group may be saturated or unsaturated and straight, branched or cyclic. Examples thereof are as exemplified above for R^{2a1} in formula (c1-1-1). The subscripts p and q are each independently an integer of 0 to 5, and r is an integer of 0 to 4.

[0284] Examples of the PAG having formula (4) include those exemplified for the PAG having formula (2) in JP-A 2017-026980.

[0285] Of the foregoing PAGs, those having an anion of formula (c1-1-1) or (c1-4) are especially preferred because of reduced acid diffusion and high solubility in solvents. Also those having formula (4') are especially preferred because of extremely reduced acid diffusion.

[0286] When used, the PAG (D) is preferably added in an amount of 0.1 to 40 parts, and more preferably 0.5 to 20 parts by weight per 80 parts by weight of the base polymer (B). As long as the amount of the PAG is in the range, good resolution is achievable and the risk of foreign particles being formed after development or during stripping of resist film is avoided. The PAG may be used alone or in admixture.

(E) Other Quencher

[0287] The resist composition may further comprise (E) a quencher other than component (A).

[0288] Onium salts having the formulae (5) and (6) are useful as the other quencher (E).



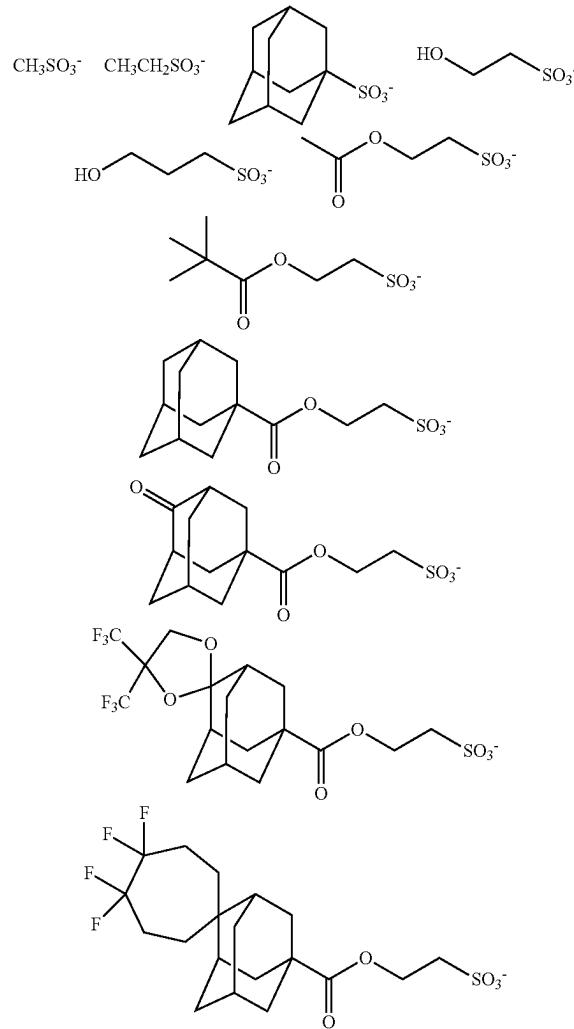
[0289] In formula (5), R^{q1} is hydrogen or a $\text{C}_1\text{-C}_{40}$ hydrocarbyl group which may contain a heteroatom, exclusive of the group wherein hydrogen bonded to the carbon atom at α -position relative to the sulfo group is substituted by fluorine or fluoroalkyl. In formula (6), R^{q2} is hydrogen or a $\text{C}_1\text{-C}_{40}$ hydrocarbyl group which may contain a heteroatom.

[0290] Examples of the $\text{C}_1\text{-C}_{40}$ hydrocarbyl group R^{q1} include $\text{C}_1\text{-C}_{40}$ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, tert-pentyl, n-hexyl, n-octyl, 2-ethylhexyl, n-nonyl, and n-decyl; $\text{C}_3\text{-C}_{40}$ cyclic saturated hydrocarbyl groups such as cyclopentyl, cyclohexyl, cyclopentylmethyl, cyclopentyl-

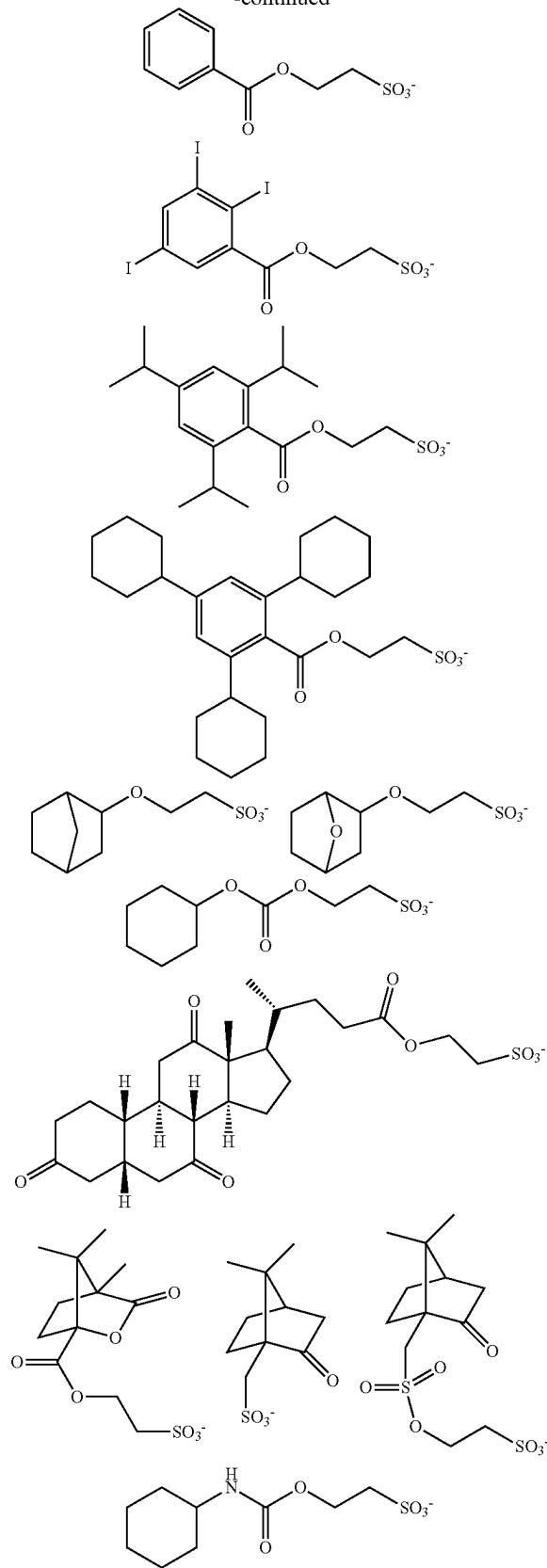
ethyl, cyclopentylbutyl, cyclohexylmethyl, cyclohexylethyl, cyclohexylbutyl, norbornyl, tricyclo[5.2.1.0^{2,6}]decyl, and adamantyl; $\text{C}_6\text{-C}_{40}$ aryl groups such as phenyl, naphthyl and anthracenyl. In the hydrocarbyl group, some or all hydrogen may be substituted by a moiety containing a heteroatom such as oxygen, sulfur, nitrogen or halogen, and some constituent $-\text{CH}_2-$ may be replaced by a moiety containing a heteroatom such as oxygen, sulfur or nitrogen, so that the group may contain a hydroxy moiety, fluorine, chlorine, bromine, iodine, cyano moiety, carbonyl moiety, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring, carboxylic anhydride ($-\text{C}(=\text{O})-\text{O}-\text{C}(=\text{O})-$), or haloalkyl moiety.

[0291] Examples of the hydrocarbyl group R^{q2} include those exemplified above for R^{q1} and fluorinated saturated hydrocarbyl groups, for example, fluorinated alkyl groups such as trifluoromethyl and trifluoroethyl, and fluorinated aryl groups such as pentafluorophenyl and 4-trifluoromethylphenyl.

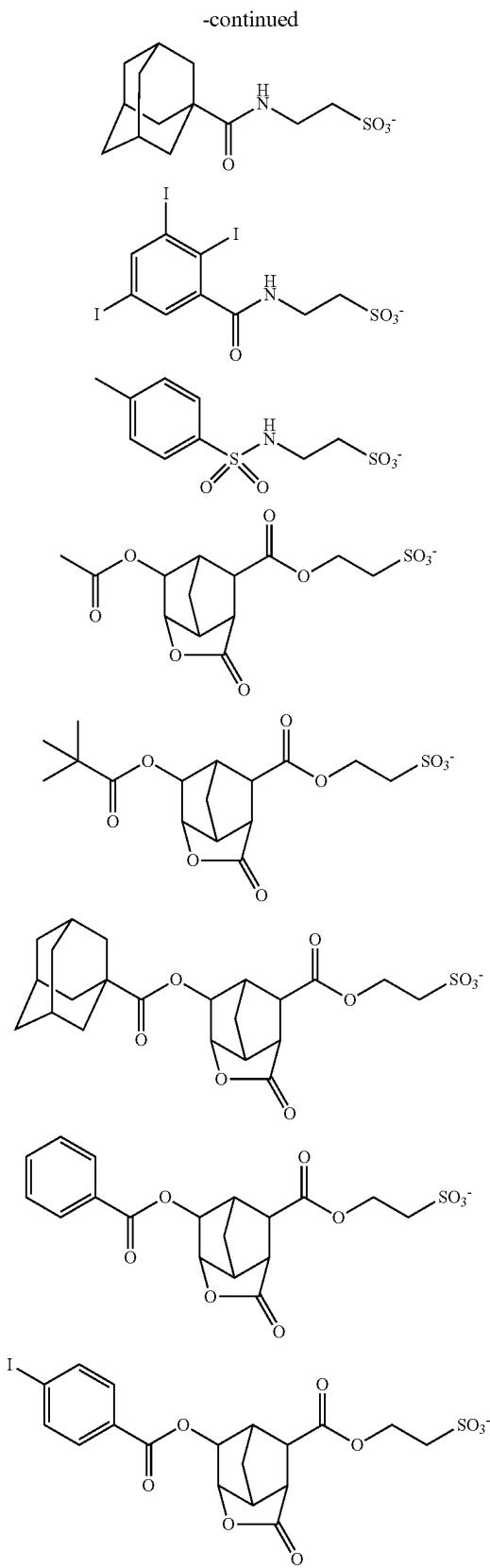
[0292] Examples of the anion in the onium salt having formula (5) are shown below, but not limited thereto.



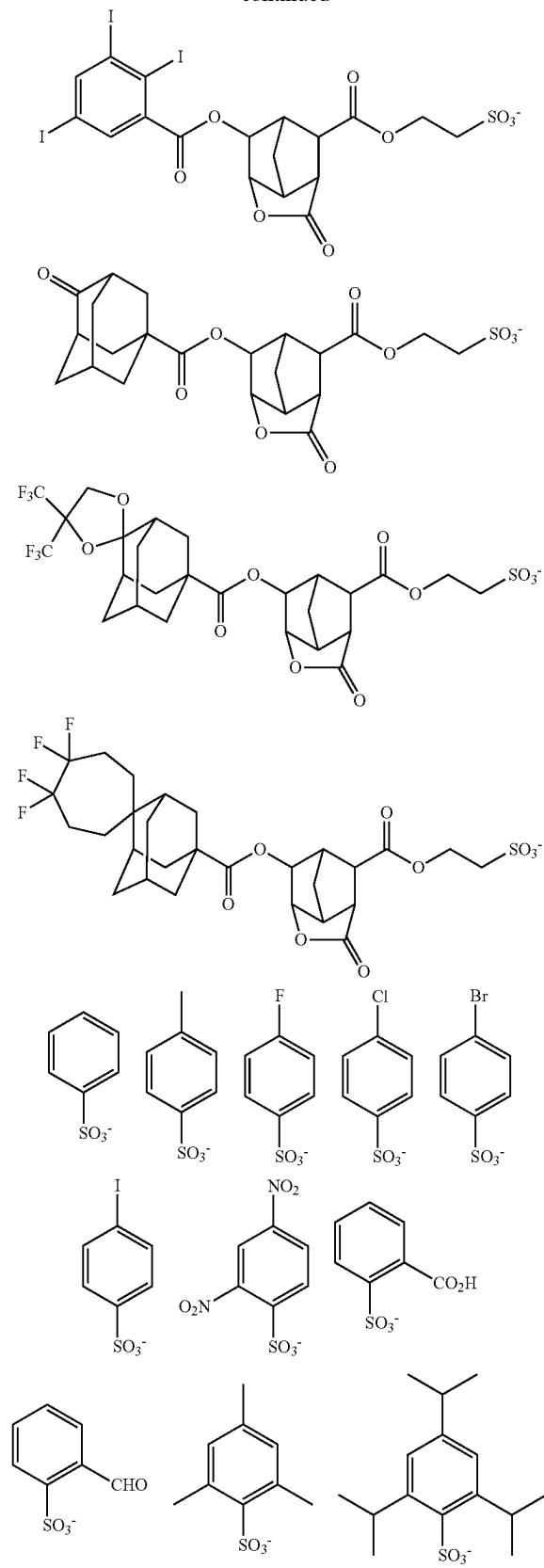
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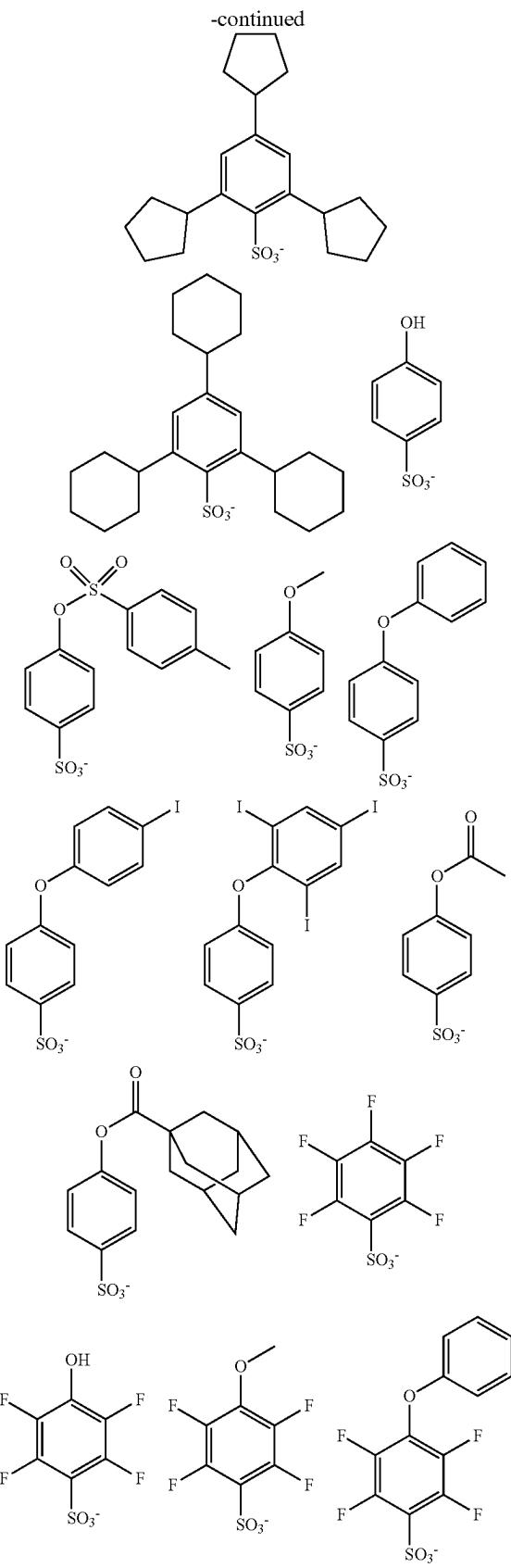
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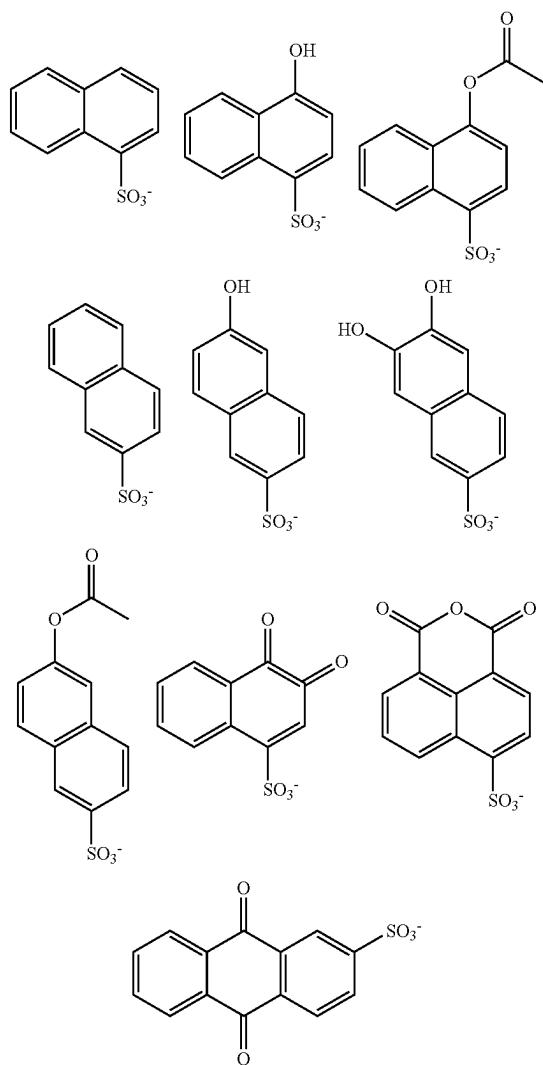
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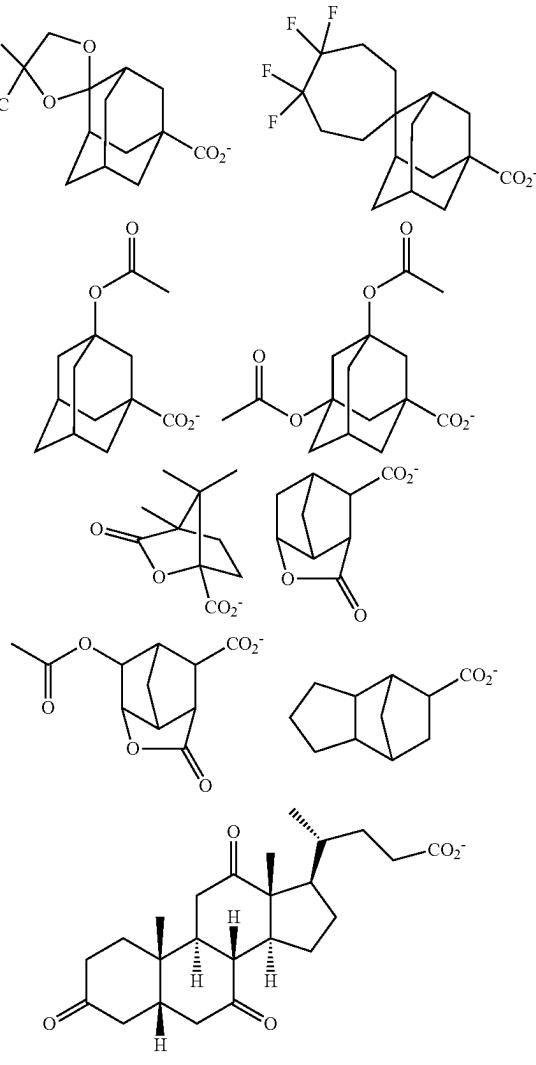
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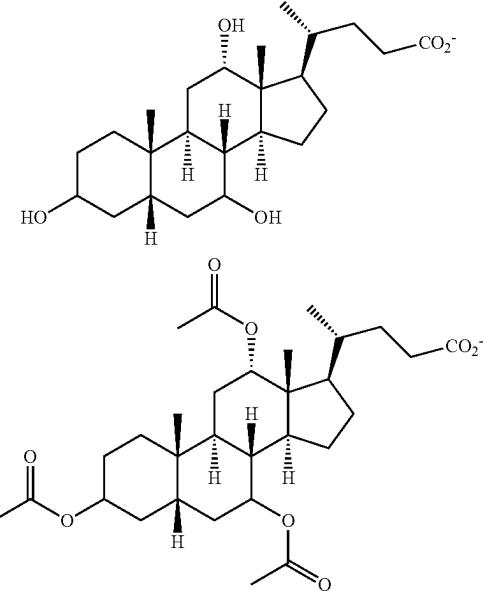
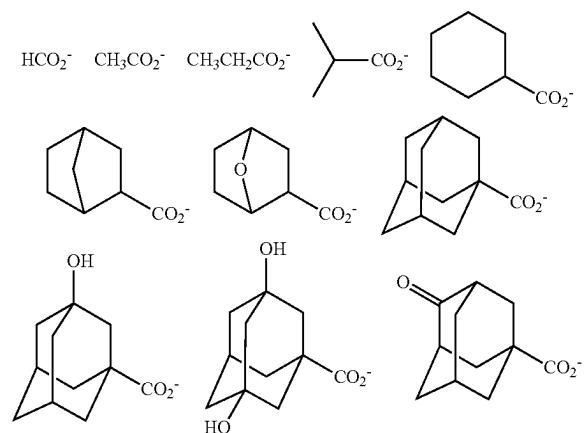
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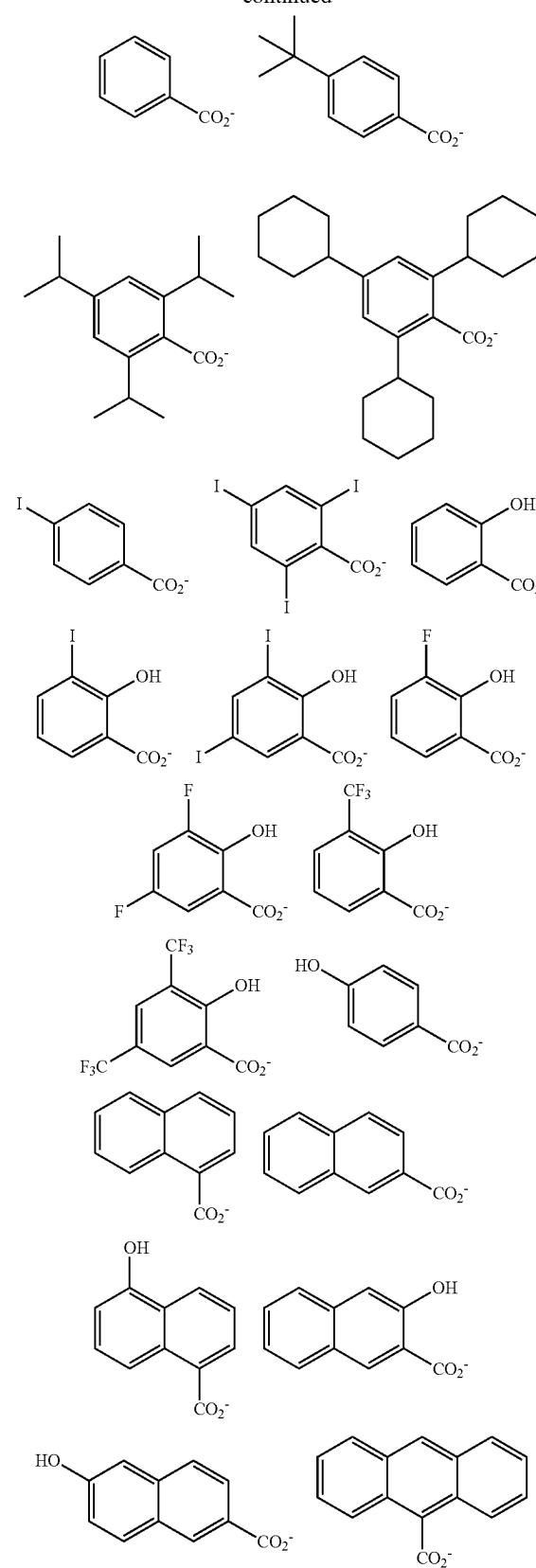
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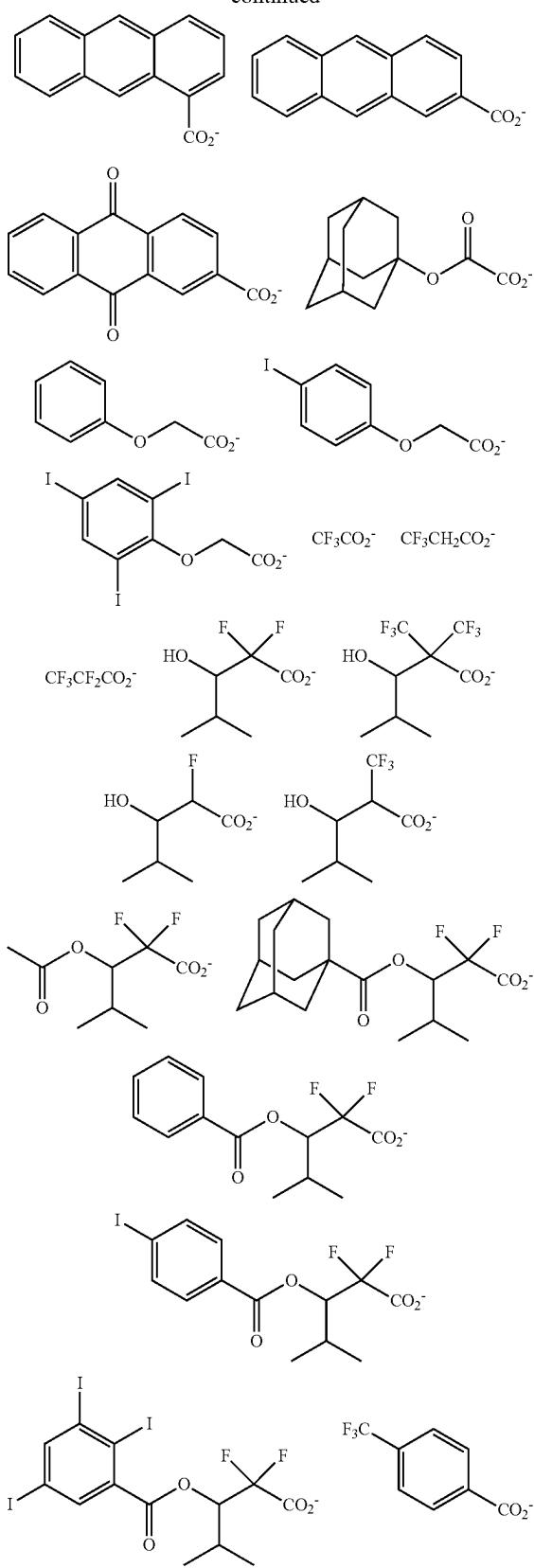
[0293] Examples of the anion in the onium salt having formula (6) are shown below, but not limited thereto.

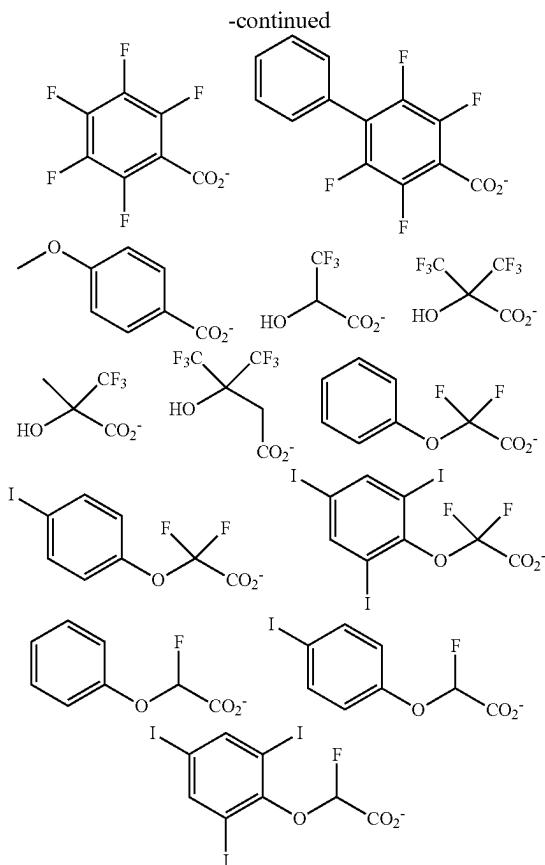


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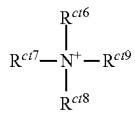
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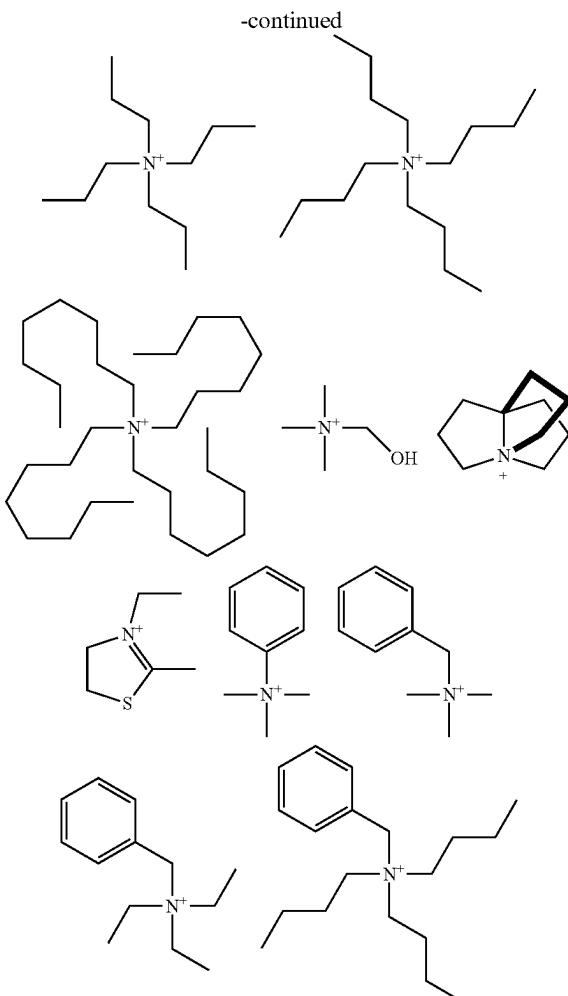
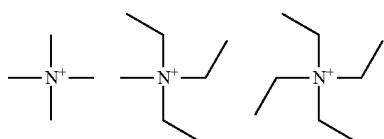
[0294] In formulae (5) and (6), Mq^+ is an onium cation, which is preferably selected from sulfonyl cations having formula (cation-1), iodonium cations having formula (cation-2), as mentioned above, and ammonium cations having the formula (cation-3).

(cation-3)



[0295] In formula (cation-3), R^{c16} to R^{c19} are each independently a C_1-C_{40} hydrocarbyl group which may contain a heteroatom. A pair of R^{c16} and R^{c17} may bond together to form a ring with the nitrogen atom to which they are attached. Examples of the hydrocarbyl group are as exemplified above for the hydrocarbyl groups R^{c1} to R^{c5} in formulae (cation-1) and (cation-2).

[0296] Examples of the ammonium cation having formula (cation-3) are shown below, but not limited thereto.



[0297] Examples of the onium salt having formula (5) or (6) include arbitrary combinations of anions with cations, both as exemplified above. These onium salts may be readily prepared by ion exchange reaction using any well-known organic chemistry technique. For the ion exchange reaction, reference may be made to JP-A 2007-145797, for example.

[0298] The onium salt having formula (5) or (6) functions as a quencher in the chemically amplified resist composition because the counter anion of the onium salt is a conjugated base of a weak acid. As used herein, the weak acid indicates an acidity insufficient to deprotect an acid labile group from an acid labile group-containing unit in the base polymer. The onium salt having formula (5) or (6) functions as a quencher when used in combination with an onium salt type PAG having a conjugated base of a strong acid (typically sulfonic acid) as the counter anion. In a system using a mixture of an onium salt capable of generating a strong acid (typically sulfonic acid) and an onium salt capable of generating a weak acid (typically carboxylic acid), if the strong acid generated from the PAG upon exposure to high-energy radiation collides with the unreacted onium salt having a weak acid anion, then a salt exchange occurs whereby the weak acid is released and an onium salt having a strong acid anion is formed. In this course, the strong acid is exchanged

into the weak acid having a low catalysis, incurring apparent deactivation of the acid for enabling to control acid diffusion.

[0299] Also useful as the other quencher (E) are onium salts having sulfonium cation and phenoxide anion sites in a common molecule as described in JP 6848776, onium salts having sulfonium cation and carboxylate anion sites in a common molecule as described in JP 6583136 and JP-A 2020-200311, and onium salts having iodonium cation and carboxylate anion sites in a common molecule as described in JP 6274755.

[0300] If a PAG capable of generating a strong acid is an onium salt, an exchange from the strong acid generated upon exposure to high-energy radiation to a weak acid can take place as mentioned above, but it rarely happens that the weak acid generated upon exposure to high-energy radiation collides with the unreacted onium salt capable of generating a strong acid to induce a salt exchange. This is because of the phenomenon that an onium cation is more likely to form an ion pair with a stronger acid anion.

[0301] When the onium salt having formula (5) or (6) is used as the quencher (E), the amount of the onium salt used is preferably 0.1 to 20 parts by weight, more preferably 0.1 to 10 parts by weight per 80 parts by weight of the base polymer (B). As long as the amount of onium salt type quencher (E) is in the range, a satisfactory resolution is available without a substantial lowering of sensitivity. The onium salt having formula (5) or (6) may be used alone or in admixture.

[0302] Nitrogen-containing compounds may also be used as the other quencher (E). Suitable nitrogen-containing compounds include primary, secondary and tertiary amine compounds, specifically amine compounds having a hydroxy group, ether bond, ester bond, lactone ring, cyano group or sulfonate ester bond, as described in JP-A 2008-111103, paragraphs [0146]-[0164](U.S. Pat. No. 7,537,880), and primary or secondary amine compounds protected with a carbamate group, as described in JP 3790649.

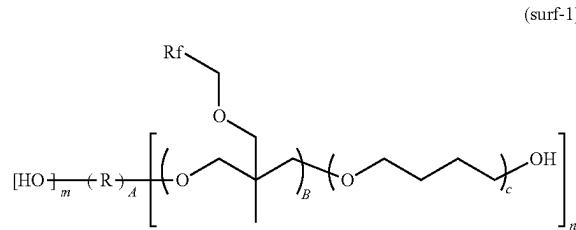
[0303] A sulfonic acid sulfonium salt having a nitrogen-containing substituent may also be used as the nitrogen-containing compound. This compound functions as a quencher in the unexposed region, but as a so-called photo-degradable base in the exposed region because it loses the quencher function in the exposed region due to neutralization thereof with the acid generated by itself. Using a photo-degradable base, the contrast between exposed and unexposed regions can be further enhanced. With respect to the photo-degradable base, reference may be made to JP-A 2009-109595 and JP-A 2012-046501, for example.

[0304] When the nitrogen-containing compound is used as the other quencher (E), the amount of the nitrogen-containing compound used is preferably 0.001 to 12 parts by weight, more preferably 0.01 to 8 parts by weight per 80 parts by weight of the base polymer (B). The nitrogen-containing compound may be used alone or in admixture.

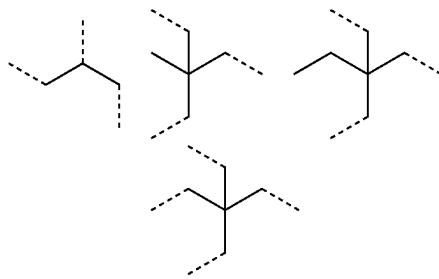
(F) Surfactant

[0305] The resist composition may further include (F) a surfactant. Preferred are a surfactant which is insoluble or substantially insoluble in water and soluble in alkaline developer, and a surfactant which is insoluble or substantially insoluble in water and alkaline developer. For the surfactant, reference should be made to those compounds described in JP-A 2010-215608 and JP-A 2011-016746.

[0306] While many examples of the surfactant which is insoluble or substantially insoluble in water and alkaline developer are described in the patent documents cited herein, preferred examples are surfactants FC-4430 (3M), Olfine® E1004 (Nissin Chemical Co., Ltd.), Surflon® 5-381, KH-20 and KH-30 (AGC Seimi Chemical Co., Ltd.). Partially fluorinated oxetane ring-opened polymers having the formula (surf-1) are also useful.



[0307] It is provided herein that R, Rf, A, B, C, m, and n are applied to only formula (surf-1), independent of their descriptions other than for the surfactant. R is a di- to tetra-valent C₂-C₅ aliphatic group. Exemplary divalent aliphatic groups include ethylene, 1,4-butylene, 1,2-propylene, 2,2-dimethyl-1,3-propylene and 1,5-pentylene. Exemplary tri- and tetra-valent groups are shown below.



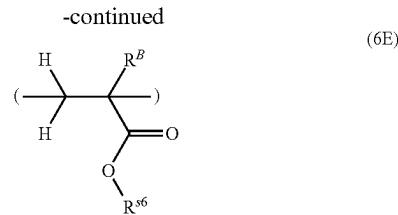
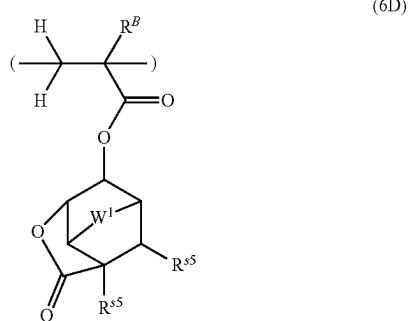
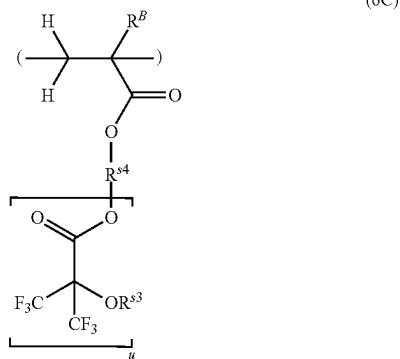
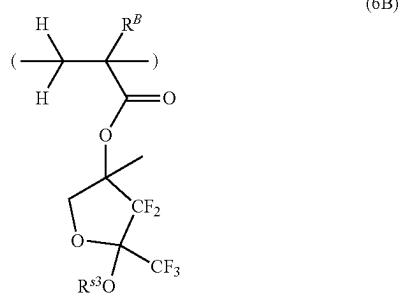
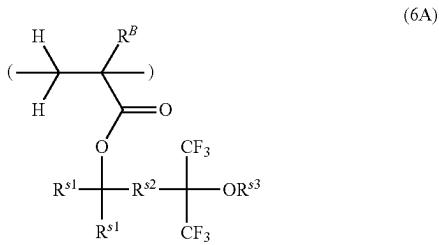
[0308] Herein the broken line denotes a valence bond. These formulae are partial structures derived from glycerol, trimethylol ethane, trimethylol propane, and pentaerythritol, respectively. Of these, 1,4-butylene and 2,2-dimethyl-1,3-propylene are preferably used.

[0309] Rf is trifluoromethyl or pentafluoroethyl, and preferably trifluoromethyl. The letter m is an integer of 0 to 3, n is an integer of 1 to 4, and the sum of m and n, which represents the valence of R, is an integer of 2 to 4. "A" is equal to 1, B is an integer of 2 to 25, and C is an integer of 0 to 10. Preferably, B is an integer of 4 to 20, and C is 0 or 1. Note that the formula (surf-1) does not prescribe the arrangement of respective constituent units while they may be arranged either blockwise or randomly. For the preparation of surfactants in the form of partially fluorinated oxetane ring-opened polymers, reference should be made to U.S. Pat. No. 5,650,483, for example.

[0310] The surfactant which is insoluble or substantially insoluble in water and soluble in alkaline developer is useful when ArF immersion lithography is applied to the resist composition in the absence of a resist protective film. In this embodiment, the surfactant has a propensity to segregate on the resist surface for achieving a function of minimizing

water penetration or leaching. The surfactant is also effective for preventing water-soluble components from being leached out of the resist film for minimizing any damage to the exposure tool. The surfactant becomes solubilized during aqueous alkaline development following exposure and PEB, and thus forms few or no foreign particles which become defects. The preferred surfactant is a polymeric surfactant which is insoluble or substantially insoluble in water, but soluble in alkaline developer, also referred to as "hydrophobic resin" in this sense, and especially which is water repellent and enhances water sliding.

[0311] Suitable polymeric surfactants include those containing repeat units of at least one type selected from the formulae (6A) to (6E).



[0312] Herein, R^B is hydrogen, fluorine, methyl or trifluoromethyl. W^1 is $-\text{CH}_2-$, $-\text{CH}_2\text{CH}_2-$, $-\text{O}-$, or two separate $-\text{H}$. R^{s1} is each independently hydrogen or a $C_1\text{-}C_{10}$ hydrocarbyl group. R^{s2} is a single bond or a $C_1\text{-}C_5$ straight or branched hydrocarbylene group. R^{s3} is each independently hydrogen, a $C_1\text{-}C_{15}$ hydrocarbyl or fluorinated hydrocarbyl group, or an acid labile group. When R^{s3} is a hydrocarbyl or fluorinated hydrocarbyl group, an ether bond or carbonyl moiety may intervene in a carbon-carbon bond. R^{s4} is a $C_1\text{-}C_{20}$ ($u+1$)-valent hydrocarbon or fluorinated hydrocarbon group, and u is an integer of 1 to 3. R^{s5} is each independently hydrogen or a group: $-\text{C}(=\text{O})-\text{O}-\text{R}^{sa}$ wherein R^{sa} is a $C_1\text{-}C_{20}$ fluorinated hydrocarbyl group. R^{s6} is a $C_1\text{-}C_{15}$ hydrocarbyl or fluorinated hydrocarbyl group in which an ether bond or carbonyl moiety may intervene in a carbon-carbon bond.

[0313] The hydrocarbyl group represented by R^{s1} may be straight, branched or cyclic and is preferably saturated. Examples thereof include $C_1\text{-}C_{10}$ alkyl groups such as methyl, ethyl, n-propyl, isopropyl, n-butyl, isobutyl, sec-butyl, tert-butyl, n-pentyl, n-hexyl, n-heptyl, n-octyl, n-nonyl, n-decyl, and $C_3\text{-}C_{10}$ cyclic saturated hydrocarbyl groups such as cyclopropyl, cyclobutyl, cyclopentyl, cyclohexyl, adamantyl, and norbornyl. Inter alia, $C_1\text{-}C_6$ hydrocarbyl groups are preferred.

[0314] The hydrocarbylene group represented by R^{s2} may be straight, branched or cyclic and is preferably saturated. Examples thereof include methylene, ethylene, propylene, butylene and pentylene.

[0315] The hydrocarbyl group represented by R^{s3} or R^{s6} may be saturated or unsaturated and straight, branched or cyclic. Examples thereof include saturated hydrocarbyl groups, and aliphatic unsaturated hydrocarbyl groups such as alkenyl and alkynyl groups, with the saturated hydrocarbyl groups being preferred. Suitable saturated hydrocarbyl groups include those exemplified for the hydrocarbyl group represented by R^{s1} as well as undecyl, dodecyl, tridecyl, tetradecyl, and pentadecyl. Examples of the fluorinated hydrocarbyl group represented by R^{s3} or R^{s6} include the foregoing hydrocarbyl groups in which some or all carbon-bonded hydrogen atoms are substituted by fluorine atoms. In these groups, an ether bond or carbonyl moiety may intervene in a carbon-carbon bond as mentioned above.

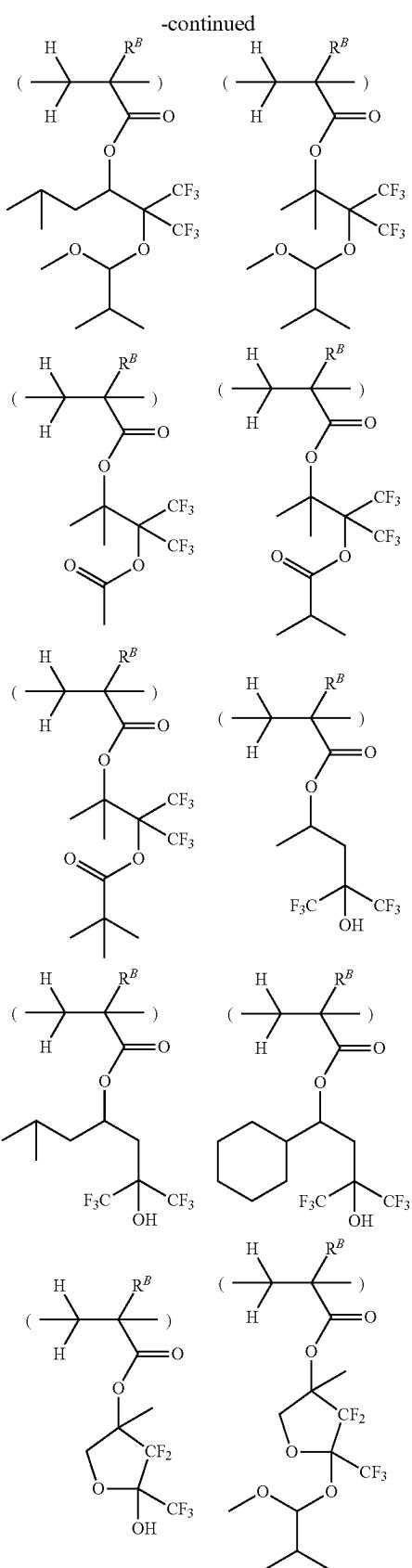
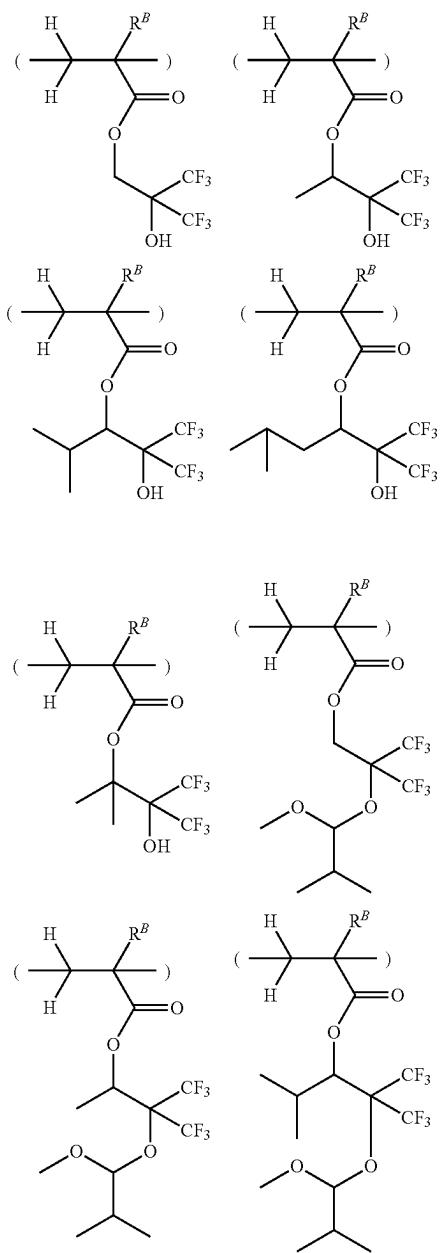
[0316] Examples of the acid labile group represented by R^{s3} include groups of the above formulae (AL-3) to (AL-5), trialkylsilyl groups in which each alkyl moiety has 1 to 6 carbon atoms, and $C_4\text{-}C_{20}$ oxoalkyl groups.

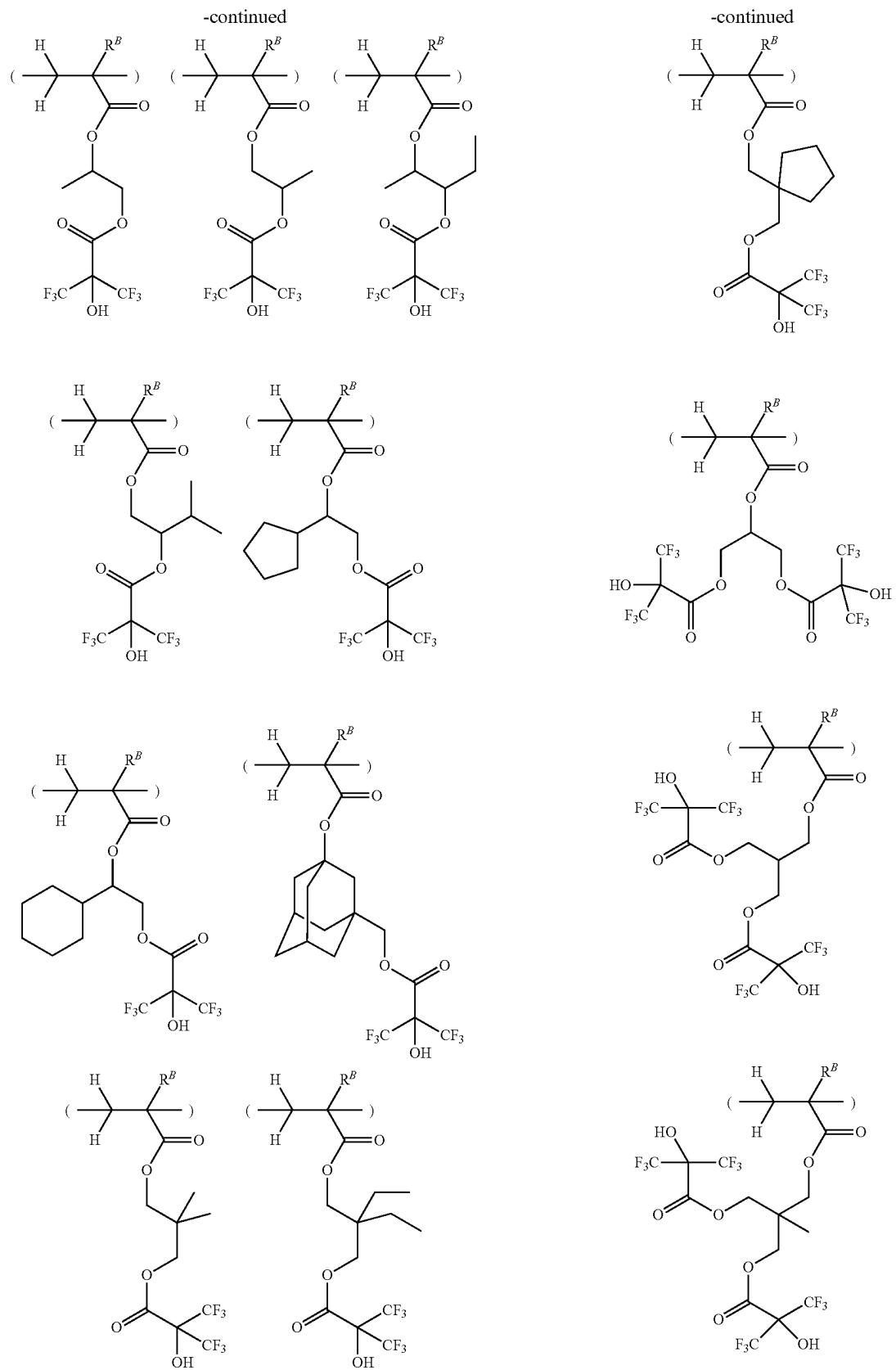
[0317] The ($u+1$)-valent hydrocarbon or fluorinated hydrocarbon group represented by R^{s4} may be straight, branched or cyclic and examples thereof include the foregoing hydrocarbyl or fluorinated hydrocarbyl groups from which "u" number of hydrogen atoms are eliminated.

[0318] The fluorinated hydrocarbyl group represented by R^5 may be straight, branched or cyclic and is preferably

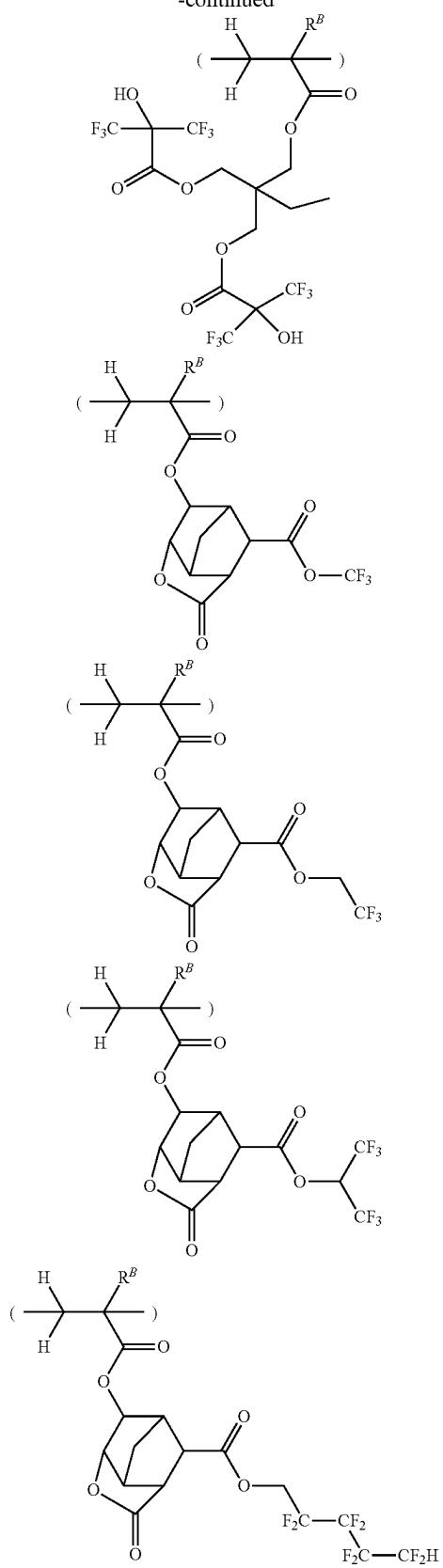
saturated. Examples thereof include the foregoing hydrocarbyl groups in which some or all hydrogen atoms are substituted by fluorine atoms. Illustrative examples include trifluoromethyl, 2,2,2-trifluoroethyl, 3,3,3-trifluoro-1-propyl, 3,3,3-trifluoro-2-propyl, 2,2,3,3-tetrafluoropropyl, 1,1,1,3,3,3-hexafluoroisopropyl, 2,2,3,3,4,4,4-heptafluorobutyl, 2,2,3,3,4,4,5,5-octafluoropentyl, 2,2,3,3,4,4,5,5,6,6,7,7-decafluoroheptyl, 2-(perfluorobutyl)ethyl, 2-(perfluorohexyl)ethyl, 2-(perfluoroctyl)ethyl, and 2-(perfluorodecyl)ethyl.

[0319] Examples of the repeat units having formulae (6A) to (6E) are shown below, but not limited thereto. Herein R^B is as defined above.

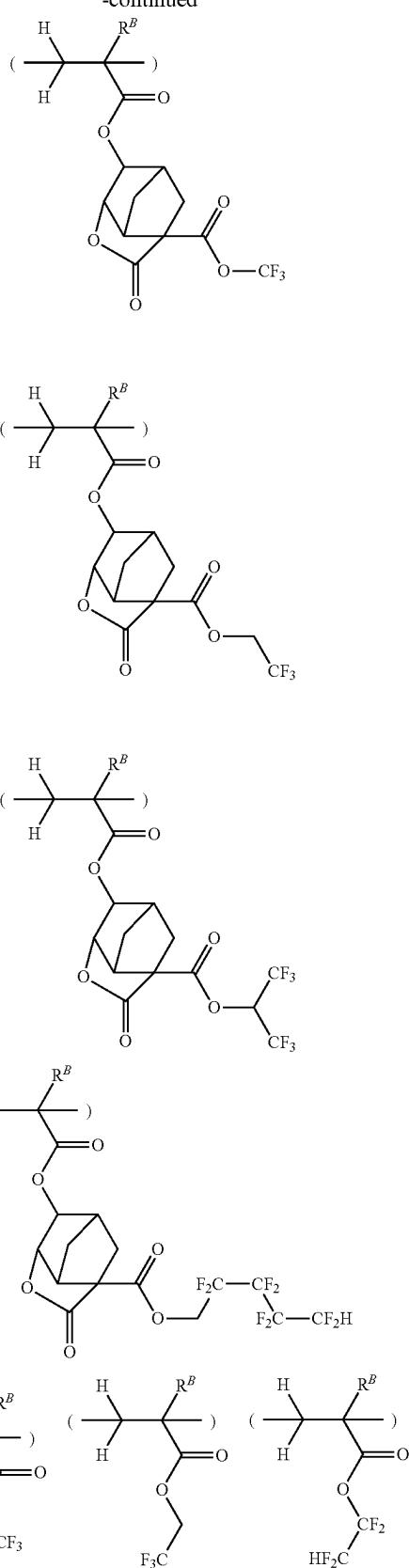


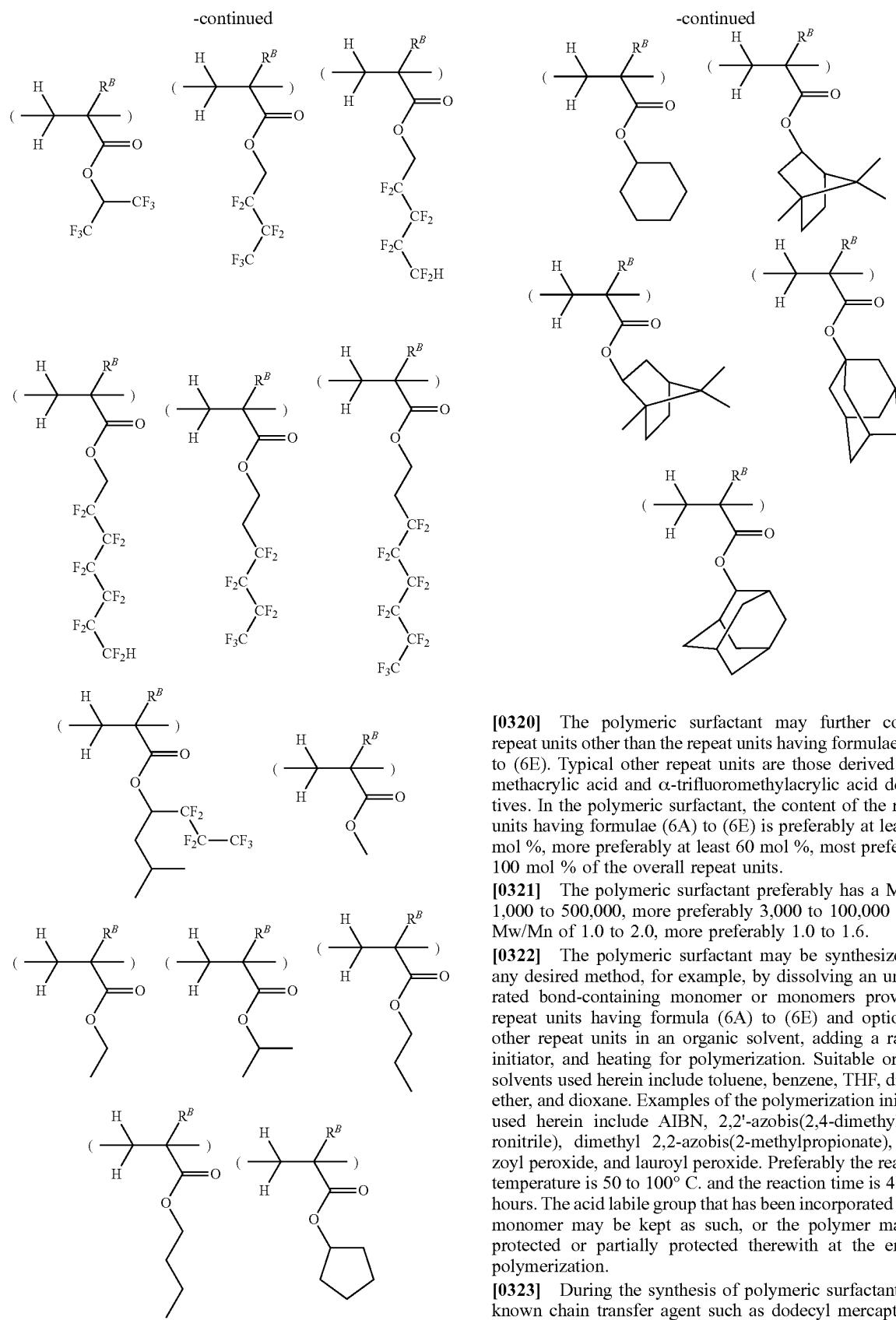


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[0320] The polymeric surfactant may further contain repeat units other than the repeat units having formulae (6A) to (6E). Typical other repeat units are those derived from methacrylic acid and α -trifluoromethylacrylic acid derivatives. In the polymeric surfactant, the content of the repeat units having formulae (6A) to (6E) is preferably at least 20 mol %, more preferably at least 60 mol %, most preferably 100 mol % of the overall repeat units.

[0321] The polymeric surfactant preferably has a Mw of 1,000 to 500,000, more preferably 3,000 to 100,000 and a Mw/Mn of 1.0 to 2.0, more preferably 1.0 to 1.6.

[0322] The polymeric surfactant may be synthesized by any desired method, for example, by dissolving an unsaturated bond-containing monomer or monomers providing repeat units having formula (6A) to (6E) and optionally other repeat units in an organic solvent, adding a radical initiator, and heating for polymerization. Suitable organic solvents used herein include toluene, benzene, THF, diethyl ether, and dioxane. Examples of the polymerization initiator used herein include AIBN, 2,2'-azobis(2,4-dimethylvaleronitrile), dimethyl 2,2-azobis(2-methylpropionate), benzoyl peroxide, and lauroyl peroxide. Preferably the reaction temperature is 50 to 100°C. and the reaction time is 4 to 24 hours. The acid labile group that has been incorporated in the monomer may be kept as such, or the polymer may be protected or partially protected therewith at the end of polymerization.

[0323] During the synthesis of polymeric surfactant, any known chain transfer agent such as dodecyl mercaptan or 2-mercaptopropanol may be added for molecular weight

control purpose. The amount of chain transfer agent added is preferably 0.01 to 10 mol % based on the total moles of monomers to be polymerized.

[0324] When the resist composition contains a surfactant (F), the amount thereof is preferably 0.1 to 50 parts by weight, and more preferably 0.5 to 10 parts by weight per 80 parts by weight of the base polymer (B). At least 0.1 part of the surfactant is effective in improving the receding contact angle with water of the resist film at its surface. Up to 50 parts of the surfactant is effective in forming a resist film having a low rate of dissolution in a developer and capable of maintaining the height of a small-size pattern formed therein. The surfactant (F) may be used alone or in admixture.

(G) Other Components

[0325] The resist composition may further comprise (G) another component, for example, a compound which is decomposed with an acid to generate another acid (i.e., acid amplifier compound), an organic acid derivative, a fluorinated alcohol, and a compound having a Mw of up to 3,000 which changes its solubility in developer under the action of an acid (i.e., dissolution inhibitor). Specifically, the acid amplifier compound is described in JP-A 2009-269953 and JP-A 2010-215608 and preferably used in an amount of 0 to 5 parts, more preferably 0 to 3 parts by weight per 80 parts by weight of the base polymer (B). An extra amount of the acid amplifier compound can make the acid diffusion control difficult and cause degradations to resolution and pattern profile. With respect to the remaining additives, reference should be made to JP-A 2009-269953 and JP-A 2010-215608.

[Process]

[0326] A further embodiment of the invention is a process of forming a pattern from the resist composition defined above by lithography. The preferred process includes the steps of applying the resist composition onto a substrate to form a resist film thereon, exposing the resist film to high-energy radiation, and developing the exposed resist film in a developer. Any desired steps may be added to the process if necessary.

[0327] The substrate used herein may be a substrate for integrated circuitry fabrication, e.g., Si, SiO₂, SiN, SiON, TiN, WSi, BPSG, SOG, organic antireflective film, etc. or a substrate for mask circuitry fabrication, e.g., Cr, CrO, CrON, MoSi₂, SiO₂, etc.

[0328] The resist composition is applied onto a substrate by a suitable coating technique such as spin coating. The coating is prebaked on a hot plate preferably at a temperature of 60 to 150° C. for 1 to 10 minutes, more preferably at 80 to 140° C. for 1 to 5 minutes. The resulting resist film preferably has a thickness of 0.05 to 2 μm.

[0329] Then the resist film is exposed to a pattern of high-energy radiation, typically KrF or ArF excimer laser, EUV or EB. On use of KrF excimer laser, ArF excimer laser or EUV, the resist film is exposed through a mask having a desired pattern, preferably in a dose of 1 to 200 mJ/cm², more preferably 10 to 100 mJ/cm². On use of EB, a pattern may be written directly or through a mask having the desired pattern, preferably in a dose of 1 to 300 pC/cm², more preferably 10 to 200 pC/cm².

[0330] The exposure may be performed by conventional lithography whereas the immersion lithography of holding a liquid having a refractive index of at least 1.0 between the resist film and the projection lens may be employed if desired. The liquid is typically water, and in this case, a protective film which is insoluble in water may be formed on the resist film.

[0331] While the water-insoluble protective film serves to prevent any components from being leached out of the resist film and to improve water sliding on the film surface, it is generally divided into two types. The first type is an organic solvent-strippable protective film which must be stripped, prior to alkaline development, with an organic solvent in which the resist film is not dissolvable. The second type is an alkali-soluble protective film which is soluble in an alkaline developer so that it can be removed simultaneously with the removal of solubilized regions of the resist film. The protective film of the second type is preferably of a material comprising a polymer having a 1,1,1,3,3-hexafluoro-2-propanol residue (which is insoluble in water and soluble in an alkaline developer) as a base in an alcohol solvent of at least 4 carbon atoms, an ether solvent of 8 to 12 carbon atoms or a mixture thereof. Alternatively, the aforementioned surfactant which is insoluble in water and soluble in an alkaline developer may be dissolved in an alcohol solvent of at least 4 carbon atoms, an ether solvent of 8 to 12 carbon atoms or a mixture thereof to form a material from which the protective film of the second type is formed.

[0332] After the exposure, the resist film may be baked (PEB), for example, on a hotplate preferably at 60 to 150° C. for 1 to 5 minutes, more preferably at 80 to 140° C. for 1 to 3 minutes.

[0333] The resist film is then developed with a developer in the form of an aqueous base solution, for example, 0.1 to 5 wt %, preferably 2 to 3 wt % aqueous solution of tetramethylammonium hydroxide (TMAH) for 0.1 to 3 minutes, preferably 0.5 to 2 minutes by conventional techniques such as dip, puddle and spray techniques. In this way, the exposed region of the resist film is dissolved away, and a desired resist pattern is formed on the substrate.

[0334] Any desired step may be added to the pattern forming process. For example, after the resist film is formed, a step of rinsing with pure water may be introduced to extract the acid generator or the like from the film surface or wash away particles. After exposure, a step of rinsing may be introduced to remove any water remaining on the film after exposure.

[0335] Also, a double patterning process may be used for pattern formation. The double patterning process includes a trench process of processing an underlay to a 1:3 trench pattern by a first step of exposure and etching, shifting the position, and forming a 1:3 trench pattern by a second step of exposure, for forming a 1:1 pattern; and a line process of processing a first underlay to a 1:3 isolated left pattern by a first step of exposure and etching, shifting the position, processing a second underlay formed below the first underlay by a second step of exposure through the 1:3 isolated left pattern, for forming a half-pitch 1:1 pattern.

[0336] In the pattern forming process, negative tone development may also be used. That is, an organic solvent may be used instead of the aqueous alkaline solution as the developer for developing and dissolving away the unexposed region of the resist film.

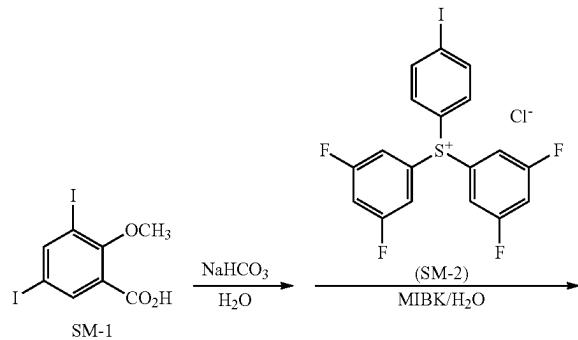
[0337] The organic solvent used as the developer is preferably selected from 2-octanone, 2-nonanone, 2-heptanone, 3-heptanone, 4-heptanone, 2-hexanone, 3-hexanone, diisobutyl ketone, methylcyclohexanone, acetophenone, methylacetophenone, propyl acetate, butyl acetate, isobutyl acetate, pentyl acetate, isopentyl acetate, butenyl acetate, propyl formate, butyl formate, isobutyl formate, pentyl formate, isopentyl formate, methyl valerate, methyl pentenoate, methyl crotonate, ethyl crotonate, methyl propionate, ethyl propionate, ethyl 3-ethoxypropionate, methyl lactate, ethyl lactate, propyl lactate, butyl lactate, isobutyl lactate, pentyl lactate, isopentyl lactate, methyl 2-hydroxyisobutyrate, ethyl 2-hydroxyisobutyrate, methyl benzoate, ethyl benzoate, phenyl acetate, benzyl acetate, methyl phenylacetate, ethyl phenylacetate, benzyl formate, phenylethyl formate, methyl 3-phenylpropionate, benzyl propionate, and 2-phenylethyl acetate. These organic solvents may be used alone or in admixture of two or more.

EXAMPLES

[0338] Synthesis Examples, Examples and Comparative Examples are given below by way of illustration and not by way of limitation. The abbreviation "pbw" is parts by weight. Analysis is made by time-of-flight mass spectrometry using the instrument, MALDI TOF-MS: S3000 by JEOL Ltd.

[1] Synthesis of Onium Salts

[Example 1-1] Synthesis of Onium Salt PDQ-1



[0339] In a reactor under nitrogen atmosphere, 4.0 g of Reactant SM-1, 1.0 g of sodium hydrogencarbonate and 20 g of water were mixed and stirred at an internal temperature of 45° C. for 1 hour. The reaction solution was cooled to room temperature. Thereafter, 5.0 g of Reactant SM-2 and 30 g of methyl isobutyl ketone were added to the solution, which was stirred at room temperature for 30 minutes. At the end of stirring, the organic layer was taken out, washed with water, and concentrated under reduced pressure. The concentrate was purified by silica gel chromatography, obtaining the target Onium Salt PDQ-1 as oily matter (amount 7.2 g, yield 83%).

[0340] PDQ-1 was analyzed by TOF-MS, with the data shown below.

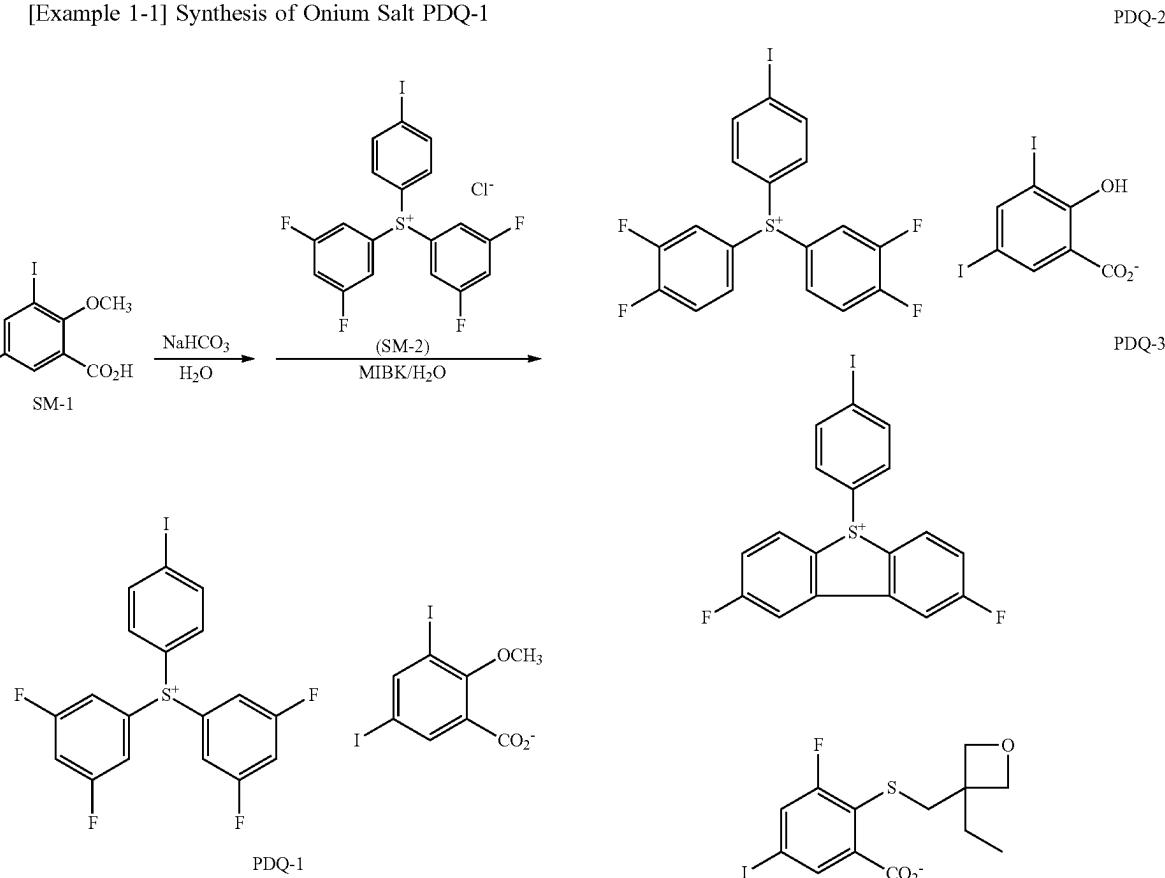
[0341] MALDI TOF-MS:

[0342] positive M^+ 461 (corresponding to $\text{C}_{18}\text{H}_{10}\text{F}_4\text{IS}^+$)

[0343] negative M^- 403 (corresponding to $\text{C}_8\text{H}_5\text{I}_2\text{O}_3^-$)

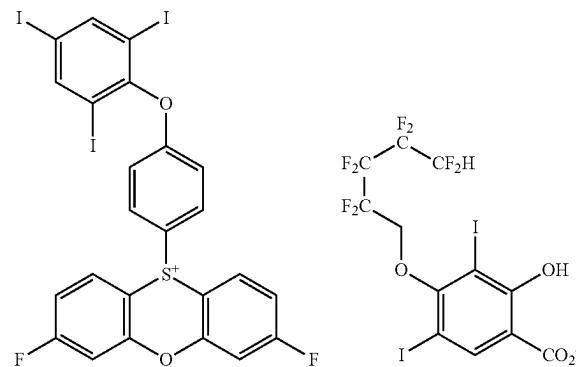
[Examples 1-2 to 1-7] Synthesis of Onium Salts
PDQ-2 to PDQ-7

[0344] Onium salts PDQ-2 to PDQ-7 shown below were synthesized using corresponding reactants and well-known organic synthesis reactions.



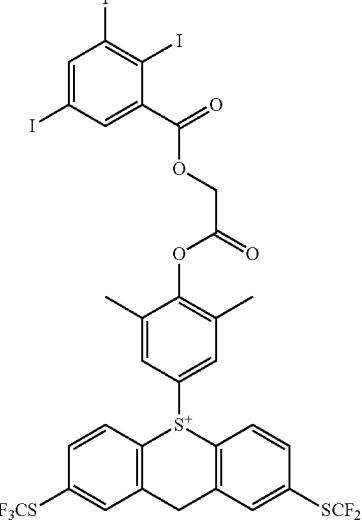
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PDQ-4

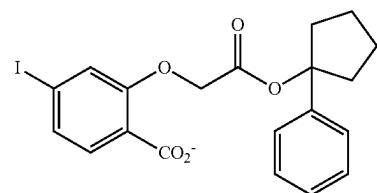
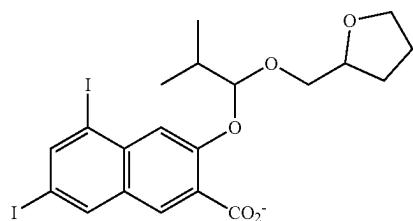
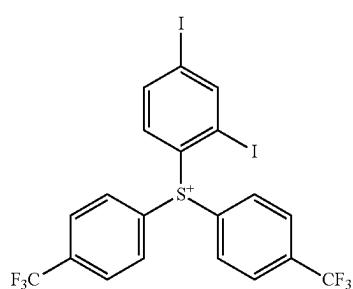


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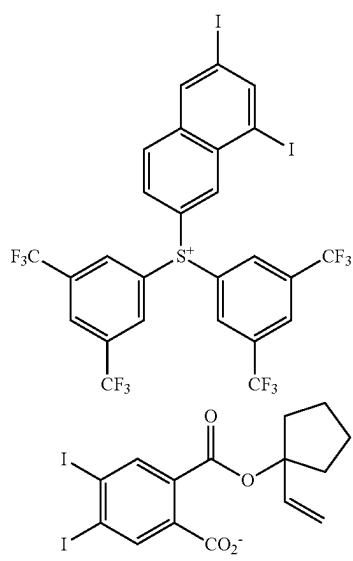
PDQ-7



PDQ-5



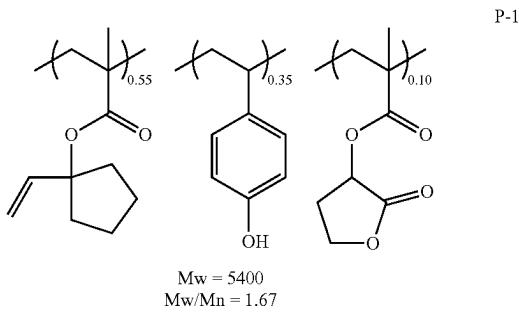
PDQ-6



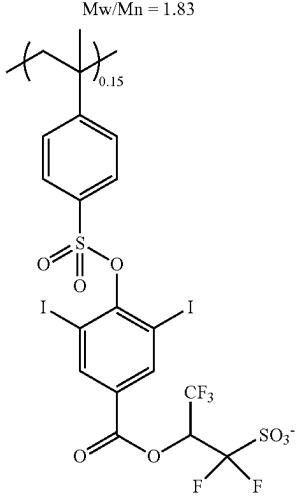
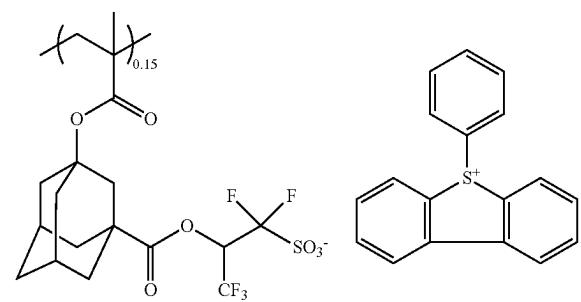
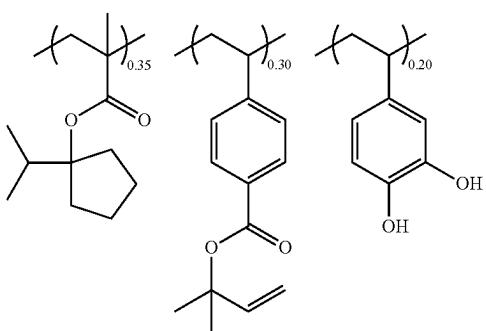
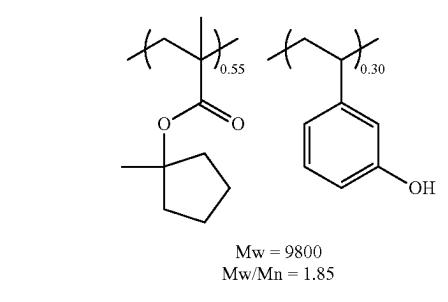
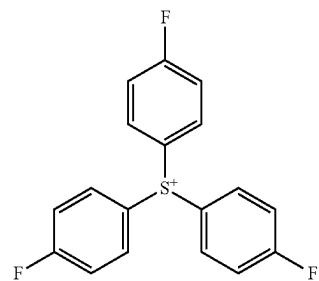
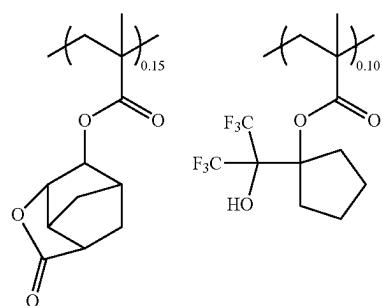
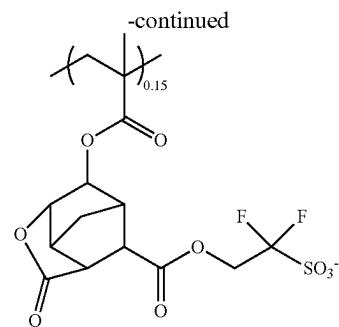
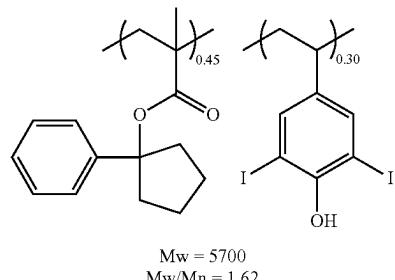
[2] Synthesis of Base Polymers

[Synthesis Example] Synthesis of Base Polymers P-1 to P-5

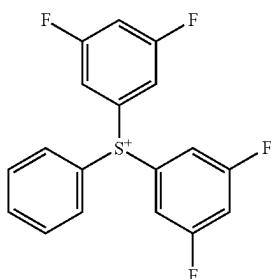
[0345] Base polymers P-1 to P-5 were synthesized by combining monomers, performing copolymerization reaction in MEK solvent, pouring the reaction solution to hexane for precipitation, washing the solid precipitate with hexane, isolation and drying. The polymer was analyzed for composition by $^1\text{H-NMR}$ spectroscopy and for Mw and Mw/Mn by GPC versus polystyrene standards using DMF solvent.



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[3] Preparation of Chemically Amplified Resist Compositions

Examples 2-1 to 2-30 and Comparative Examples
1-1 to 1-20

[0346] Chemically amplified resist compositions (R-1 to R-30, CR-1 to CR-20) in solution form were prepared by dissolving a quencher (PDQ-1 to PDQ-7) or comparative quencher (PDQ-A to PDQ-D), photoacid generator (PAG-X and PAG-Y), base polymer (P-1 to P-5), and other quencher (AQ-1 and AQ-2) in a solvent containing 0.01 wt % of surfactant A in accordance with the formulation shown in Tables 1 and 2, and filtering through a Teflon® filter with a pore size of 0.2 µm.

TABLE 1

	Resist composition	Base polymer (pbw)	Quencher (pbw)	Photoacid generator (pbw)	Other quencher (pbw)	Solvent 1 (pbw)	Solvent 2 (pbw)
Example	2-1	R-1	P-1 (80)	PDQ-1 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-2	R-2	P-1 (80)	PDQ-2 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-3	R-3	P-1 (80)	PDQ-3 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-4	R-4	P-1 (80)	PDQ-4 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-5	R-5	P-1 (80)	PDQ-5 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-6	R-6	P-1 (80)	PDQ-6 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-7	R-7	P-1 (80)	PDQ-7 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-8	R-8	P-1 (80)	PDQ-1 (5)	PAG-Y (15)	—	PGMEA (2200) DAA (900)
	2-9	R-9	P-1 (80)	PDQ-1 (2.5)	PAG-X (15)	AQ-1 (2.5)	PGMEA (2200) DAA (900)
	2-10	R-10	P-1 (80)	PDQ-2 (3)	PAG-Y (15)	AQ-2 (2)	PGMEA (2200) DAA (900)
	2-11	R-11	P-2 (80)	PDQ-1 (5)	PAG-X (14)	—	PGMEA (2200) DAA (900)
	2-12	R-12	P-2 (80)	PDQ-2 (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	2-13	R-13	P-2 (80)	PDQ-4 (5)	PAG-Y (14)	—	PGMEA (2200) DAA (900)
	2-14	R-14	P-2 (80)	PDQ-6 (5)	PAG-Y (15)	—	PGMEA (2200) DAA (900)
	2-15	R-15	P-2 (80)	PDQ-1 (4)	PAG-X (15)	AQ-1 (2)	PGMEA (2200) DAA (900)
	2-16	R-16	P-3 (80)	PDQ-1 (5)	—	—	PGMEA (2200) DAA (900)
	2-17	R-17	P-3 (80)	PDQ-2 (5)	—	—	PGMEA (2200) DAA (900)
	2-18	R-18	P-3 (80)	PDQ-3 (5)	—	—	PGMEA (2200) DAA (900)
	2-19	R-19	P-3 (80)	PDQ-4 (5)	PAG-X (5)	—	PGMEA (2200) DAA (900)
	2-20	R-20	P-3 (80)	PDQ-2 (3)	—	AQ-1 (2)	PGMEA (2200) DAA (900)
	2-21	R-21	P-4 (80)	PDQ-1 (5)	—	—	PGMEA (2200) DAA (900)
	2-22	R-22	P-4 (80)	PDQ-2 (5)	—	—	PGMEA (2200) DAA (900)
	2-23	R-23	P-4 (80)	PDQ-5 (5)	—	—	PGMEA (2200) DAA (900)
	2-24	R-24	P-4 (80)	PDQ-6 (6)	PAG-Y (5)	—	PGMEA (2200) DAA (900)
	2-25	R-25	P-4 (80)	PDQ-2 (5)	—	—	PGMEA (2200) DAA (900)
	2-26	R-26	P-5 (80)	PDQ-1 (5)	—	—	PGMEA (2200) DAA (900)
	2-27	R-27	P-5 (80)	PDQ-2 (5)	—	—	PGMEA (2200) DAA (900)
	2-28	R-28	P-5 (80)	PDQ-7 (3)	PAG-Y (5)	AQ-2 (2)	PGMEA (2200) DAA (900)
	2-29	R-29	P-5 (80)	PDQ-3 (5)	—	—	PGMEA (2200) DAA (900)
	2-30	R-30	P-5 (80)	PDQ-2 (2.5)	—	AQ-1 (2.5)	PGMEA (2200) DAA (900)

TABLE 2

	Resist composition	Base polymer (pbw)	Comparative Quencher (pbw)	Photoacid generator (pbw)	Other quencher (pbw)	Solvent 1 (pbw)	Solvent 2 (pbw)
Comparative Example	1-1	CR-1	P-1 (80)	PDQ-A (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	1-2	CR-2	P-1 (80)	PDQ-B (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	1-3	CR-3	P-1 (80)	PDQ-C (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	1-4	CR-4	P-1 (80)	PDQ-D (5)	PAG-X (15)	—	PGMEA (2200) DAA (900)
	1-5	CR-5	P-1 (80)	PDQ-A (5)	PAG-Y (15)	—	PGMEA (2200) DAA (900)
	1-6	CR-6	P-1 (80)	PDQ-B (5)	PAG-Y (15)	—	PGMEA (2200) DAA (900)
	1-7	CR-7	P-1 (80)	PDQ-C (2.5)	PAG-X (15)	AQ-1 (2.5)	PGMEA (2200) DAA (900)
	1-8	CR-8	P-1 (80)	PDQ-D (3)	PAG-Y (15)	AQ-2 (2)	PGMEA (2200) DAA (900)

TABLE 2-continued

Resist composition	Base polymer (pbw)	Comparative Quencher (pbw)	Photoacid generator (pbw)	Other quencher (pbw)	Solvent 1 (pbw)	Solvent 2 (pbw)
1-9	CR-9	P-2 (80)	PDQ-A (5)	PAG-X (15)	—	PGMEA (2200)
1-10	CR-10	P-2 (80)	PDQ-B (5)	PAG-X (15)	—	PGMEA (2200)
1-11	CR-11	P-2 (80)	PDQ-C (4)	PAG-X (15)	AQ-1 (2)	PGMEA (2200)
1-12	CR-12	P-3 (80)	PDQ-A (5)	—	—	PGMEA (2200)
1-13	CR-13	P-3 (80)	PDQ-C (5)	—	—	PGMEA (2200)
1-14	CR-14	P-3 (80)	PDQ-D (3)	—	AQ-1 (2)	PGMEA (2200)
1-15	CR-15	P-4 (80)	PDQ-A (5)	—	—	PGMEA (2200)
1-16	CR-16	P-4 (80)	PDQ-D (5)	—	—	PGMEA (2200)
1-17	CR-17	P-4 (80)	PDQ-C (6)	PAG-Y (5)	—	PGMEA (2200)
1-18	CR-18	P-5 (80)	PDQ-A (5)	—	—	PGMEA (2200)
1-19	CR-19	P-5 (80)	PDQ-B (3)	PAG-Y (5)	AQ-2 (2)	PGMEA (2200)
1-20	CR-20	P-5 (80)	PDQ-C (5)	—	—	PGMEA (2200)

[0347] The solvents, photoacid generators PAG-X and PAG-Y, comparative quenchers PDQ-A to PDQ-D, other quenchers AQ-1 and AQ-2, and surfactant A in Tables 1 and 2 are identified below.

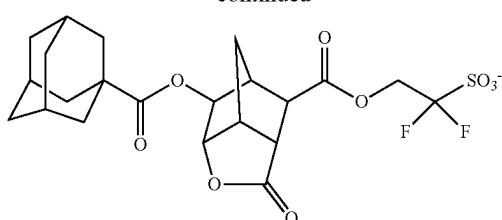
Solvent:

[0348] PGMEA (propylene glycol monomethyl ether acetate)

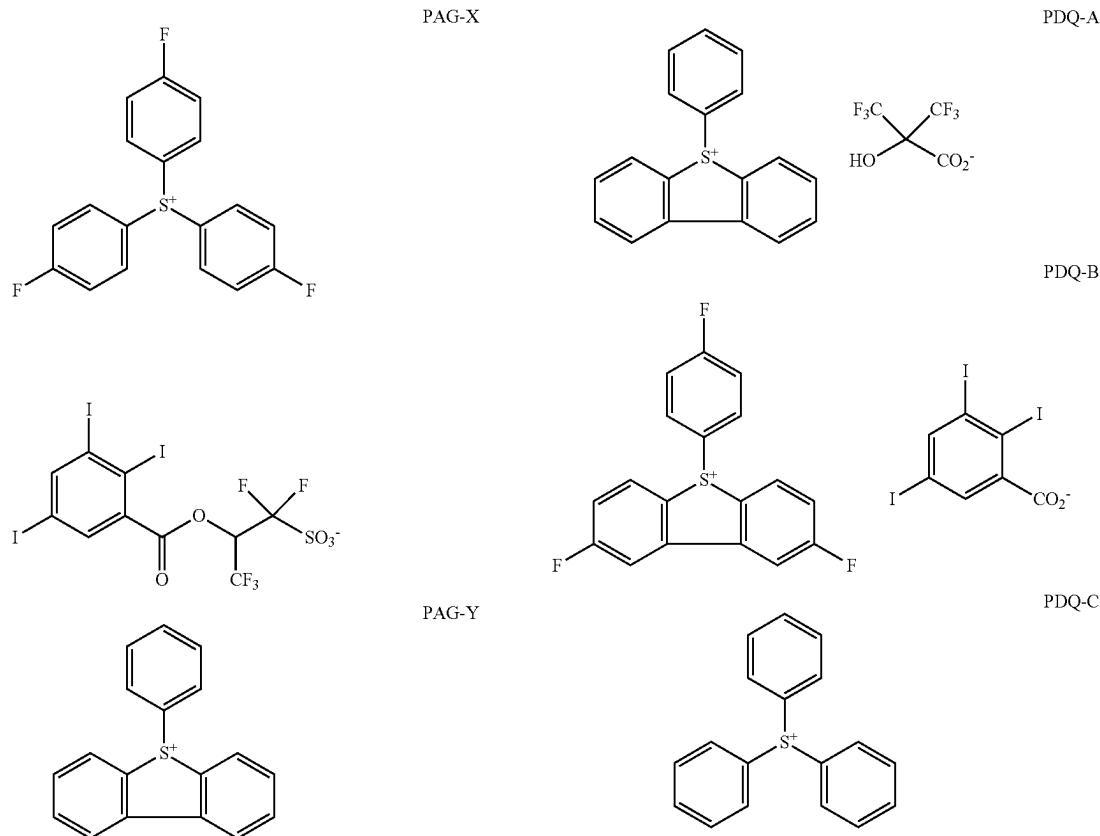
[0349] DAA (diacetone alcohol)

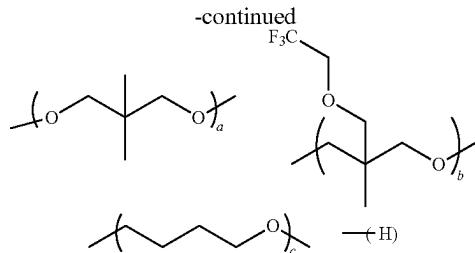
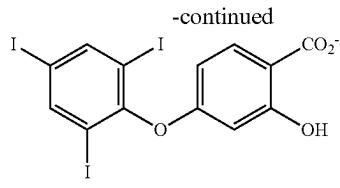
[0350] Photoacid generators: PAG-X and PAG-Y

-continued

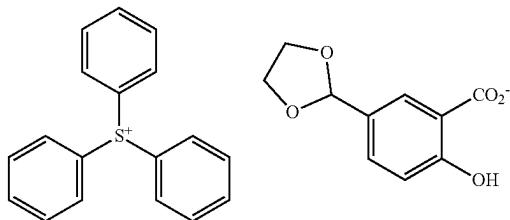


[0351] Comparative quenchers: PDQ-A to PDQ-D

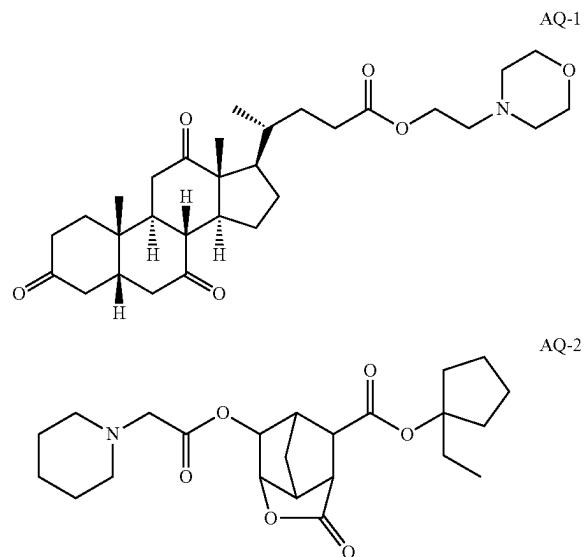




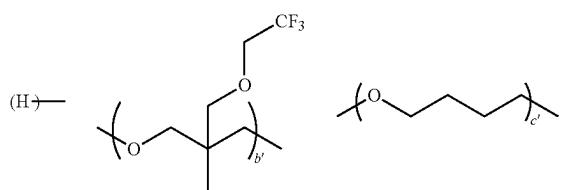
PDQ-D



[0352] Other quenchers: AQ-1 and AQ-2



[0353] Surfactant A: 3-methyl-3-(2,2,2-trifluoroethoxymethyl)oxetane/tetrahydrofuran/2,2-dimethyl-1,3-propane diol copolymer (Omnova Solutions, Inc.)



[0354] a: (b+b'): (c+c')=1: 4-7; 0.01-1 (molar ratio)

[0355] Mw=1,500

[4] EUV Lithography Test 1

Examples 3-1 to 3-30 and Comparative Examples 2-1 to 2-20

[0356] Each of the chemically amplified resist compositions (R-1 to R-30, CR-1 to CR-20) was spin coated on a silicon substrate having a 20-nm coating of silicon-containing spin-on hard mask SHB-A940 (Shin-Etsu Chemical Co., Ltd., silicon content 43 wt %) and prebaked on a hotplate at 100° C. for 60 seconds to form a resist film of 50 nm thick. Using an EUV scanner NXE3400 (ASML, NA 0.33, σ 0.9/0.6, dipole illumination), the resist film was exposed to EUV through a mask bearing a LS pattern having a size of 18 nm and a pitch of 36 nm (on-wafer size) while varying the dose and focus (dose pitch: 1 mJ/cm², focus pitch: 0.020 μ m). The resist film was baked (PEB) on a hotplate at the temperature shown in Tables 3 and 4 for 60 seconds and puddle developed in a 2.38 wt % TMAH aqueous solution for 30 seconds, rinsed with a rinse fluid containing surfactant, and spin dried to form a positive pattern.

[0357] The LS pattern as developed was observed under CD-SEM (CG6300, Hitachi High-Technologies Corp.) whereupon sensitivity, EL, LWR, DOF and collapse limit were evaluated by the following methods. The results are shown in Tables 3 and 4.

[Evaluation of Sensitivity]

[0358] The optimum dose E_{op} (mJ/cm²) which provided a LS pattern with a line width of 18 nm and a pitch of 36 nm was determined as an index of sensitivity. A smaller value indicates a higher sensitivity.

[Evaluation of EL]

[0359] The exposure dose which provided a LS pattern with a space width of 18 nm \pm 10% (i.e., 16.2 to 19.8 nm) was determined. EL (%) is calculated from the exposure doses according to the following equation:

$$EL(\%) = (|E_1 - E_2| / E_{op}) \times 100$$

[0360] wherein E₁ is an optimum exposure dose which provides a LS pattern with a line width of 16.2 nm and a pitch of 36 nm, E₂ is an optimum exposure dose which provides a LS pattern with a line width of 19.8 nm and a pitch of 36 nm, and E_{op} is an optimum exposure dose which provides a LS pattern with a line width of 18 nm and a pitch of 36 nm. A greater value indicates better performance.

[Evaluation of LWR]

[0361] For the LS pattern formed by exposure at the optimum dose E_{op}, the line width was measured at 10 longitudinally spaced apart points, from which a 3-fold value (36) of the standard deviation (6) was determined and reported as LWR. A smaller value of 36 indicates a pattern having small roughness and uniform line width.

[Evaluation of DOF]

[0362] As an index of DOF, a range of focus which provided a LS pattern with a size of 18 nm±10% (i.e., 16.2

to 19.8 nm) was determined. A greater value indicates a wider DOF.

[Evaluation of Collapse Limit of Line Pattern]

[0363] For the LS pattern formed by exposure at the dose corresponding to the optimum focus, the line width was measured at 10 longitudinally spaced apart points. The minimum line size above which lines could be resolved without collapse was determined and reported as collapse limit. A smaller value indicates better collapse limit.

TABLE 3

	Resist composition	PEB temp. (° C.)	E _{op} (mJ/cm ²)	EL (%)	LWR (nm)	DOF (nm)	Collapse limit (nm)	
Example	3-1	R-1	100	33	18	2.5	110	11.1
	3-2	R-2	100	34	18	2.5	120	11.3
	3-3	R-3	100	34	17	2.6	110	10.9
	3-4	R-4	95	35	17	2.7	110	11.3
	3-5	R-5	100	34	18	2.7	120	11.2
	3-6	R-6	100	33	18	2.6	100	11.4
	3-7	R-7	105	34	17	2.7	120	11.4
	3-8	R-8	100	35	16	2.6	110	10.8
	3-9	R-9	100	35	17	2.7	100	11.4
	3-10	R-10	100	34	18	2.8	120	11.1
	3-11	R-11	105	35	17	2.8	100	10.9
	3-12	R-12	100	34	17	2.7	110	11.1
	3-13	R-13	95	33	16	2.8	120	10.8
	3-14	R-14	100	36	18	2.6	110	10.8
	3-15	R-15	100	35	16	2.6	100	11
	3-16	R-16	100	34	17	2.5	110	11.1
	3-17	R-17	100	36	16	2.7	120	11.2
	3-18	R-18	100	34	18	2.6	110	11.3
	3-19	R-19	100	36	16	2.6	120	11.5
	3-20	R-20	100	35	17	2.5	100	11.3
	3-21	R-21	100	36	16	2.8	120	11.3
	3-22	R-22	105	33	17	2.7	100	11.4
	3-23	R-23	100	34	18	2.5	110	11.4
	3-24	R-24	100	36	16	2.6	120	11.2
	3-25	R-25	105	34	17	2.7	120	11.2
	3-26	R-26	100	35	16	2.7	110	10.9
	3-27	R-27	95	34	18	2.8	100	10.8
	3-28	R-28	105	35	17	2.6	120	11.1
	3-29	R-29	100	34	18	2.5	100	11.2
	3-30	R-30	95	35	18	2.6	110	11.1

TABLE 4

	Resist composition	PEB temp. (° C.)	E _{op} (mJ/cm ²)	EL (%)	LWR (nm)	DOF (nm)	Collapse limit (nm)	
Comparative Example	2-1	CR-1	100	39	12	3.5	60	14.3
	2-2	CR-2	100	37	13	3.1	80	12.8
	2-3	CR-3	105	38	14	3.1	70	12.8
	2-4	CR-4	100	39	14	3.2	80	12.9
	2-5	CR-5	100	39	12	3.2	80	13.1
	2-6	CR-6	100	40	14	3.2	80	13.2
	2-7	CR-7	100	41	14	3.1	90	12.8
	2-8	CR-8	100	39	13	3.4	70	12.6
	2-9	CR-9	105	38	14	3.2	70	13.1
	2-10	CR-10	100	38	12	3.3	80	13.1
	2-11	CR-11	100	38	14	3.1	90	13
	2-12	CR-12	100	39	14	3.1	80	13.1
	2-13	CR-13	100	38	13	3.2	90	12.8
	2-14	CR-14	95	41	13	3.4	70	12.7
	2-15	CR-15	105	39	14	3.5	100	13.3
	2-16	CR-16	95	40	13	3.2	70	13.1
	2-17	CR-17	100	38	14	3.4	90	12.8
	2-18	CR-18	100	39	14	3.2	70	12.5
	2-19	CR-19	100	41	13	3.4	70	12.6
	2-20	CR-20	100	39	14	3.2	80	13.1

[0364] It is demonstrated in Tables 3 and 4 that chemically amplified resist compositions comprising quenchers within the scope of the invention exhibit a high sensitivity and improved values of EL, LWR and DOF. Small values of collapse limit attest that in forming a small-size pattern, the pattern is resistant to collapse. The resist compositions are useful in the EUV lithography process.

[5] EUV Lithography Test 2

Examples 4-1 to 4-30 and Comparative Examples 3-1 to 3-20

[0365] Each of the chemically amplified resist compositions (R-1 to R-30, CR-1 to CR-20) was spin coated on a silicon substrate having a 20-nm coating of silicon-containing spin-on hard mask SHB-A940 (Shin-Etsu Chemical Co., Ltd., silicon content 43 wt %) and prebaked on a hotplate at 105° C. for 60 seconds to form a resist film of 50 nm thick. Using an EUV scanner NXE3400 (ASML, NA 0.33, σ0.9/0.6, quadrupole illumination), the resist film was exposed to EUV through a mask bearing a hole pattern having a pitch of 46 nm+20% bias (on-wafer size). The resist film was baked (PEB) on a hotplate at the temperature shown in Tables 5 and 6 for 60 seconds and developed in a 2.38 wt % TMAH aqueous solution for 30 seconds to form a hole pattern having a size of 23 nm.

[0366] The pattern as developed was observed under CD-SEM (CG6300, Hitachi High-Technologies Corp.). The dose (mJ/cm^2) at which a pattern with a hole size of 23 nm was printed was determined as an index of sensitivity. The size of 50 holes was measured, from which a 3-fold value (3σ) of the standard deviation (σ) was determined as a dimensional variation (or CDU). The results are shown in Tables 5 and 6.

TABLE 5

		Resist composition	PEB temp. (° C.)	Eop (mJ/cm^2)	CDU (nm)
Example	4-1	R-1	90	24	2.4
	4-2	R-2	90	24	2.4
	4-3	R-3	95	23	2.4
	4-4	R-4	90	24	2.6
	4-5	R-5	90	25	2.4
	4-6	R-6	90	24	2.6
	4-7	R-7	95	23	2.5
	4-8	R-8	95	24	2.4
	4-9	R-9	90	24	2.3
	4-10	R-10	95	23	2.4
	4-11	R-11	95	25	2.6
	4-12	R-12	90	24	2.5
	4-13	R-13	90	25	2.4
	4-14	R-14	95	24	2.4
	4-15	R-15	95	24	2.6
	4-16	R-16	85	23	2.3
	4-17	R-17	95	24	2.5
	4-18	R-18	90	24	2.5

TABLE 5-continued

	Resist composition	PEB temp. (° C.)	Eop (mJ/cm^2)	CDU (nm)
	4-19	R-19	95	25
	4-20	R-20	90	24
	4-21	R-21	90	24
	4-22	R-22	90	25
	4-23	R-23	95	23
	4-24	R-24	90	24
	4-25	R-25	90	25
	4-26	R-26	85	25
	4-27	R-27	95	23
	4-28	R-28	90	24
	4-29	R-29	90	26
	4-30	R-30	95	25

TABLE 6

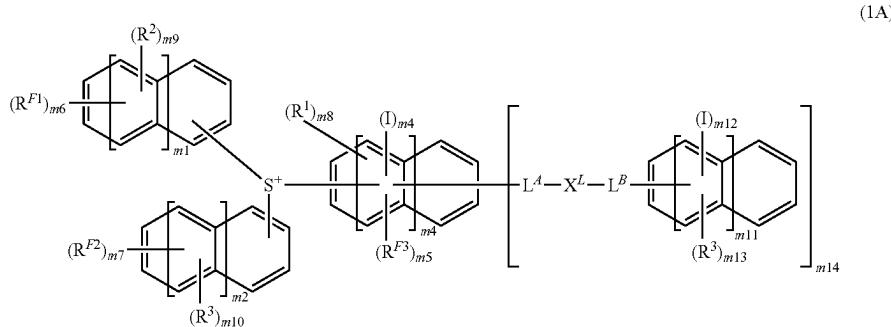
	Resist composition	PEB temp. (° C.)	Eop (mJ/cm^2)	CDU (nm)
Comparative Example	3-1 CR-1	90	32	3.2
	3-2 CR-2	90	28	2.9
	3-3 CR-3	95	27	2.8
	3-4 CR-4	90	29	2.8
	3-5 CR-5	95	31	3.1
	3-6 CR-6	85	30	3.1
	3-7 CR-7	90	29	2.8
	3-8 CR-8	90	29	2.7
	3-9 CR-9	90	31	2.8
	3-10 CR-10	95	29	2.8
	3-11 CR-11	90	28	3.1
	3-12 CR-12	90	28	2.8
	3-13 CR-13	95	30	2.7
	3-14 CR-14	90	28	3.2
	3-15 CR-15	90	29	2.8
	3-16 CR-16	90	28	3.1
	3-17 CR-17	95	29	3.0
	3-18 CR-18	90	28	2.8
	3-19 CR-19	85	31	2.7
	3-20 CR-20	90	30	2.9

[0367] It is demonstrated in Tables 5 and 6 that chemically amplified resist compositions within the scope of the invention exhibit a high sensitivity and satisfactory CDU.

[0368] Japanese Patent Application No. 2024-022670 is incorporated herein by reference. Although some preferred embodiments have been described, many modifications and variations may be made thereto in light of the above teachings. It is therefore to be understood that the invention may be practiced otherwise than as specifically described without departing from the scope of the appended claims.

The invention claimed is:

1. An onium salt consisting of a cation having the formula (1A) and an anion having the formula (1B):



wherein m1 is 0 or 1, m2 is 0 or 1, m3 is 0 or 1, m4 is an integer of 0 to 4, m5 is an integer of 0 to 4, m6 is an integer of 0 to 6, m7 is an integer of 0 to 6, m8 is an integer of 0 to 2, m9 is an integer of 0 to 2, m10 is an integer of 0 to 2, m11 is 0 or 1, m12 is an integer of 0 to 4, m13 is an integer of 0 to 2, m14 is an integer of 0 to 2, meeting $0 \leq m_6 + m_9 \leq 4$ in case of $m_1 = 0$ and $0 \leq m_6 + m_9 \leq 6$ in case of m_11 , $0 \leq m_7 + m_{10} \leq 4$ in case of $m_2 = 0$ and $0 \leq m_7 + m_{10} \leq 6$ in case of $m_2 = 1$, $1 \leq m_4 + m_5 + m_8 + m_{14} \leq 4$ in case of $m_3 = 0$ and $1 \leq m_4 + m_5 + m_8 + m_{14} \leq 6$ in case of $m_3 = 1$, $0 \leq m_{12} + m_{13} \leq 4$ in case of $m_{11} = 0$ and $0 \leq m_{12} + m_{13} \leq 6$ in case of $m_{11} = 1$, and $m_4 + m_{12} \geq 1$,

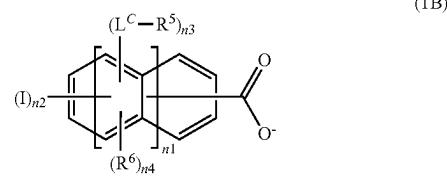
R^{F1} to R^{F3} are each independently fluorine, a C_1 - C_6 fluorinated saturated hydrocarbyl group, C_1 - C_6 fluorinated saturated hydrocarboxy group, or C_1 - C_6 fluorinated saturated hydrocarbylthio group, a plurality of R^{F1} may be identical or different when m_6 is 2 or more, a plurality of R^{F2} may be identical or different when m_7 is 2 or more, a plurality of R^{F3} may be identical or different when m_5 is 2 or more,

R^1 to R^4 each are halogen exclusive of iodine and fluorine, nitro group, cyano group, a C_1 - C_{20} hydrocarbyl group which may contain a heteroatom, C_1 - C_{20} hydrocarboxy group which may contain a heteroatom, or C_1 - C_{20} hydrocarbylthio group which may contain a heteroatom, with the proviso that when m_8 is 2, two R^1 may be identical or different and two R^1 may bond together to form a ring with the carbon atoms to which they are attached, when m_9 is 2, two R^2 may be identical or different and two R^2 may bond together to form a ring with the carbon atoms to which they are attached, when m_{10} is 2, two R^3 may be identical or different and two R^3 may bond together to form a ring with the carbon atoms to which they are attached, when m_{13} is 2, two R^4 may be identical or different and two R^4 may bond together to form a ring with the carbon atoms to which they are attached,

the aromatic rings directly bonded to S^+ in the sulfonyum cation may bond together to form a ring with S^+ ,

L^A and L^B are each independently a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond, and

X^L is a single bond or a C_1 - C_{40} hydrocarbylene group which may contain a heteroatom;

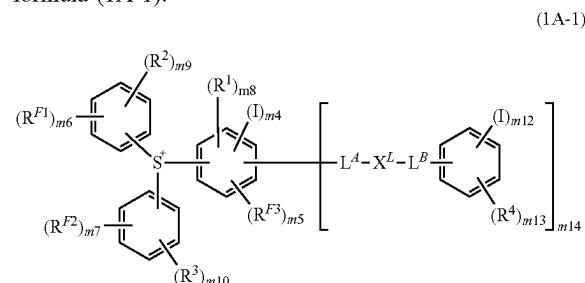


wherein n1 is 0 or 1, n2 is an integer of 1 to 4, n3 is 1 or 2, n4 is an integer of 0 to 4, meeting $2 \leq n_2 + n_3 + n_4 \leq 5$ in case of $n_1 = 0$ and $2 \leq n_2 + n_3 + n_4 \leq 7$ in case of $n_1 = 1$, L^C is a single bond, oxygen, sulfur, ester bond or carbonate bond,

R^5 is hydrogen or a C_1 - C_{20} hydrocarbyl group which may contain a heteroatom when L^C is a single bond, and hydrogen, a C_1 - C_{20} hydrocarbyl group (exclusive of acid labile group) which may contain a heteroatom, or acid labile group when L^C is oxygen, sulfur, ester bond or carbonate bond, and

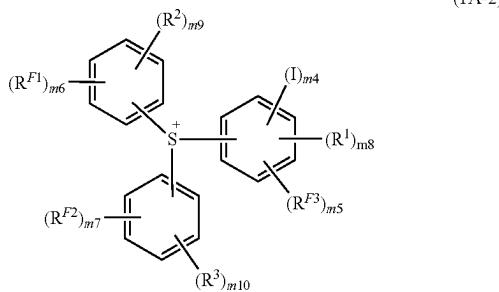
R^6 is halogen exclusive of iodine, a nitro group, cyano group, C_1 - C_{20} hydrocarbyl group which may contain a heteroatom, C_1 - C_{20} hydrocarboxy group which may contain a heteroatom, or C_1 - C_{20} hydrocarbylthio group which may contain a heteroatom.

2. The onium salt of claim 1 wherein the cation has the formula (1A-1):



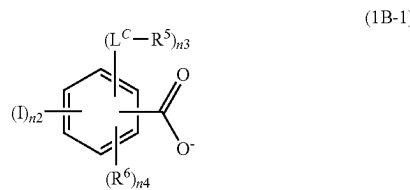
wherein m_4 to m_{10} , m_{12} to m_{14} , R^{F1} to R^{F3} , R^1 to R^4 , L^A , L^B and X^L are as defined above.

3. The onium salt of claim **2** wherein the cation has the formula (1A-2):



wherein m4 to m10, R^{F1} to R^{F3}, and R¹ to R³ are as defined above.

4. The onium salt of claim **1** wherein the anion has the formula (1B-1):

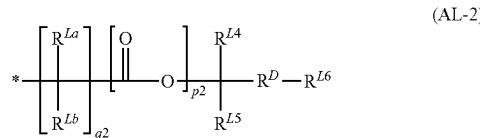
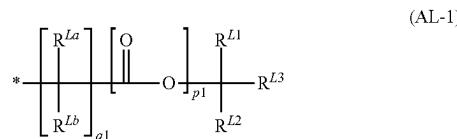


wherein n2 to n4, L^C, R⁵ and R⁶ are as defined above.

5. The onium salt of claim **1** wherein L^C is oxygen or ester bond.

6. The onium salt of claim **1** wherein L^C is oxygen, sulfur, ester bond or carbonate bond and R⁵ is an acid labile group.

7. The onium salt of claim **1** wherein the acid labile group has the formula (AL-1) or (AL-2):



wherein p1 and p2 are each independently 0 or 1, q1 and q2 are each independently an integer of 0 to 4,

R^{L1}, R^{L2} and R^{L3} are each independently a C₁-C₁₂ hydrocarbyl group in which some —CH₂— may be replaced by —O— or —S—, when the hydrocarbyl group contains an aromatic ring, some or all of the hydrogen atoms in the aromatic ring may be substituted by halogen, cyano moiety, nitro moiety, optionally halogenated C₁-C₄ alkyl moiety, or optionally halogenated C₁-C₄ alkoxy moiety, R^{L1} and R^{L2} may bond together to form a ring with the carbon atom to

which they are attached, some —CH₂— in the ring may be replaced by —O— or —S—,

R^{L4} and R^{L5} are each independently hydrogen or a C₁-C₁₀ hydrocarbyl group, R^{L6} is a C₁-C₂₀ hydrocarbyl group in which some —CH₂— may be replaced by —O— or —S—, R^{L5} and R^{L6} may bond together to form a C₃-C₂₀ heterocyclic group with the carbon atom and L^D to which they are attached, some —CH₂— in the heterocyclic group may be replaced by —O— or —S—,

L^D is —O— or —S—,

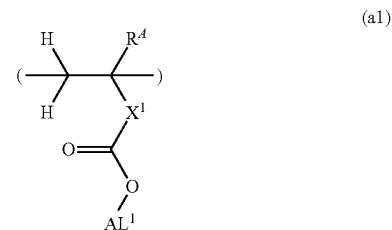
R^{La} to R^{Ld} are each independently hydrogen or a C₁-C₂₀ hydrocarbyl group which may contain a heteroatom, and

* designates a point of attachment to the adjacent oxygen or sulfur.

8. A quencher in the form of the onium salt of claim **1**.

9. A chemically amplified resist composition comprising the quencher of claim **8**.

10. The resist composition of claim **9**, further comprising a base polymer comprising repeat units having the formula (a1):

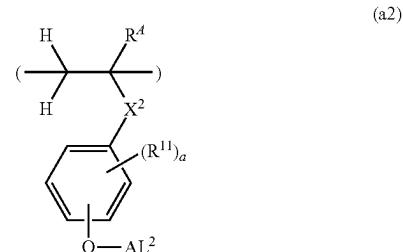


wherein R⁴ is hydrogen, fluorine, methyl or trifluoromethyl,

X¹ is a single bond, phenylene group, naphthylene group, *—C(=O)—O—X¹¹— or *—C(=O)—NH—X¹¹—, the phenylene or naphthylene group may be substituted with an optionally fluorinated C₁-C₁₀ alkoxy moiety or halogen, X¹¹ is a C₁-C₁₀ saturated hydrocarbylene group which may contain a hydroxy moiety, ether bond, ester bond or lactone ring, or phenylene or naphthylene group, * designates a point of attachment to the carbon atom in the backbone, and

AL¹ is an acid labile group.

11. The resist composition of claim **10** wherein the base polymer further comprises repeat units having the formula (a2):



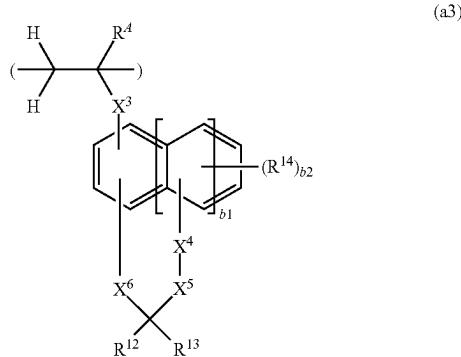
wherein R^4 is hydrogen, fluorine, methyl or trifluoromethyl,

X^2 is a single bond or $*—C(=O)—O—$, * designates a point of attachment to the carbon atom in the backbone,

R^{11} is halogen, cyano, a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, a C_1-C_{20} hydrocarbyloxy group which may contain a heteroatom, a C_2-C_{20} hydrocarbylcarbonyl group which may contain a heteroatom, a C_2-C_{20} hydrocarbylcarbonyloxy group which may contain a heteroatom, or a C_2-C_{20} hydrocarbyloxycarbonyl group which may contain a heteroatom,

AL^2 is an acid labile group, and
a is an integer of 0 to 4.

12. The resist composition of claim 10 wherein the base polymer further comprises repeat units having the formula (a3):



wherein b_1 is 0 or 1, b_2 is an integer of 0 to 3 in case of $b_1=0$ and an integer of 0 to 5 in case of $b_1=1$,

R^4 is hydrogen, fluorine, methyl or trifluoromethyl,

X^3 is a single bond, $*—C(=O)—O—$ or $*—C(=O)—NH—$, * designates a point of attachment to the carbon atom in the backbone,

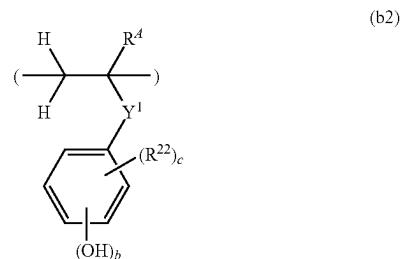
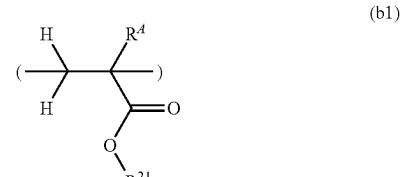
R^{12} and R^{13} are each independently hydrogen or a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, R^{12} and R^{13} may bond together to form a ring with the carbon atom to which they are attached,

R^{14} is halogen, hydroxy, cyano, nitro, a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, a C_1-C_{20} hydrocarbyloxy group which may contain a heteroatom, a C_2-C_{20} hydrocarbyloxycarbonyl group which may contain a heteroatom, a C_1-C_{20} hydrocarbythio group which may contain a heteroatom, or $—N(R^{14A})(R^{14B})$, R^{14A} and R^{14B} are each independently hydrogen or a C_1-C_6 hydrocarbyl group, a plurality of R^{14} may bond together to form a ring with the carbon atoms on the aromatic ring to which they are attached when b_2 is 2 or more,

X^4 is a single bond, C_1-C_4 aliphatic hydrocarbylene group, carbonyl group, sulfonyl group, or a group obtained by combining the foregoing,

X^5 and X^6 are each independently oxygen or sulfur, X^4 and X^6 are bonded to vicinal carbon atoms on the aromatic ring.

13. The resist composition of claim 10 wherein the base polymer further comprises repeat units having the formula (b1) or (b2):



wherein R^4 is each independently hydrogen, fluorine, methyl or trifluoromethyl,

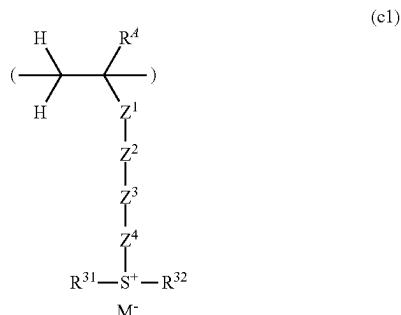
Y^1 is a single bond or $*—C(=O)—O—$, * designates a point of attachment to the carbon atom in the backbone,

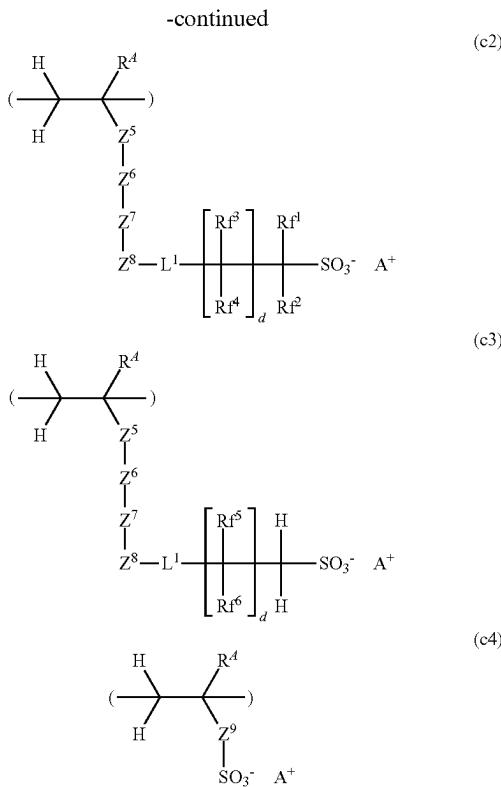
R^{21} is hydrogen or a C_1-C_{20} group containing at least one structure selected from among hydroxy other than phenolic hydroxy, cyano, carbonyl, carboxy, ether bond, ester bond, sulfonate ester bond, carbonate bond, lactone ring, sultone ring and carboxylic anhydride ($—C(=O)—O—C(=O)—$),

R^{22} is halogen, hydroxy, carboxy, nitro, cyano, a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, a C_1-C_{20} hydrocarbyloxy group which may contain a heteroatom, a C_2-C_{20} hydrocarbylcarbonyl group which may contain a heteroatom, a C_2-C_{20} hydrocarbylcarbonyloxy group which may contain a heteroatom, or a C_2-C_{20} hydrocarbyloxycarbonyl group which may contain a heteroatom,

b is an integer of 1 to 4, c is an integer of 0 to 4, and $b+c$ is from 1 to 5.

14. The resist composition of claim 10 wherein the base polymer further comprises repeat units of at least one type selected from repeat units having the formulae (c1) to (c4):





wherein R^A is each independently hydrogen, fluorine, methyl or trifluoromethyl,
 Z^1 is a single bond or optionally substituted phenylene group,
 Z^2 is a single bond, $**-C(=O)-O-Z^{21}-$, $**-C(=O)-NH-Z^{21}-$, or $**-O-Z^{21}-$, Z^{21} is a C_1-C_6 aliphatic hydrocarbylene group, phenylene group or a divalent group obtained by combining the foregoing, which may contain halogen, a carbonyl moiety, ester bond, ether bond or hydroxy moiety,
 Z^3 is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond,
 Z^4 is a single bond, or a C_1-C_6 aliphatic hydrocarbylene group, phenylene group or a divalent group obtained by combining the foregoing, which may contain halogen, carbonyl moiety, ester bond, ether bond or hydroxy moiety,
 Z^5 is each independently a single bond, optionally substituted phenylene group, naphthylene group, or $*-C(=O)-O-Z^{51}$, Z^{51} is a C_1-C_{10} aliphatic hydrocarbylene group which may contain halogen, hydroxy moiety, ether bond, ester bond or lactone ring, or phenylene or naphthylene group,
 Z^6 is a single bond, ether bond, ester bond, amide bond, sulfonate ester bond, sulfonamide bond, carbonate bond or carbamate bond,
 Z^7 is each independently a single bond, $***-Z^{71}-C(=O)-O-$, $***-C(=O)-NH-Z^{71}-$, or $***-$

$O-Z^{71}-$, Z^{71} is a C_1-C_{20} hydrocarbylene group which may contain a heteroatom,

Z^8 is each independently a single bond, $***-Z^{81}-C(=O)-O-$, $***-C(=O)-NH-Z^{81}-$, or $***-O-Z^{81}-$, Z^{81} is a C_1-C_{20} hydrocarbylene group which may contain a heteroatom,

Z^9 is a single bond, methylene, ethylene, phenylene, fluorinated phenylene, trifluoromethyl-substituted phenylene, $*-C(=O)-O-Z^{91}-$, $*-C(=O)-N(H)-Z^{91}-$, or $*-O-Z^{91}-$, Z^{91} is a C_1-C_6 aliphatic hydrocarbylene group, phenylene group, fluorinated phenylene group or trifluoromethyl-substituted phenylene group, which may contain a carbonyl moiety, ester bond, ether bond or hydroxy moiety,

* designates a point of attachment to the carbon atom in the backbone, ** designates a point of attachment to Z^1 , *** designates a point of attachment to Z^6 , **** designates a point of attachment to Z^7 ,

R^{31} and R^{32} are each independently a C_1-C_{20} hydrocarbyl group which may contain a heteroatom, R^{31} and R^{32} may bond together to form a ring with the sulfur atom to which they are attached,

L^1 is a single bond, ether bond, ester bond, carbonyl group, sulfonate ester bond, carbonate bond or carbamate bond,

Rf^1 and Rf^2 are each independently fluorine or a C_1-C_6 fluorinated saturated hydrocarbyl group,

Rf^3 and Rf^4 are each independently hydrogen, fluorine, or a C_1-C_6 fluorinated saturated hydrocarbyl group, Rf^5 and Rf^6 are each independently hydrogen, fluorine, or a C_1-C_6 fluorinated saturated hydrocarbyl group, excluding that all Rf^5 and Rf^6 are hydrogen at the same time,

M^- is a non-nucleophilic counter ion,

A^+ is an onium cation, and

d is 0, 1, 2 or 3.

15. The resist composition of claim 9, further comprising an organic solvent.

16. The resist composition of claim 9, further comprising a photoacid generator capable of generating a strong acid.

17. The resist composition of claim 8, further comprising another quencher other than the quencher.

18. The resist composition of claim 9, further comprising a surfactant.

19. A pattern forming process comprising the steps of applying the chemically amplified resist composition of claim 9 onto a substrate to form a resist film thereon, exposing the resist film to high-energy radiation, and developing the exposed resist film in a developer.

20. The pattern forming process of claim 19 wherein the high-energy radiation is KrF excimer laser radiation, ArF excimer laser radiation, EB or EUV of wavelength 3 to 15 nm.

* * * *